JAEGER ELEKTRONIK

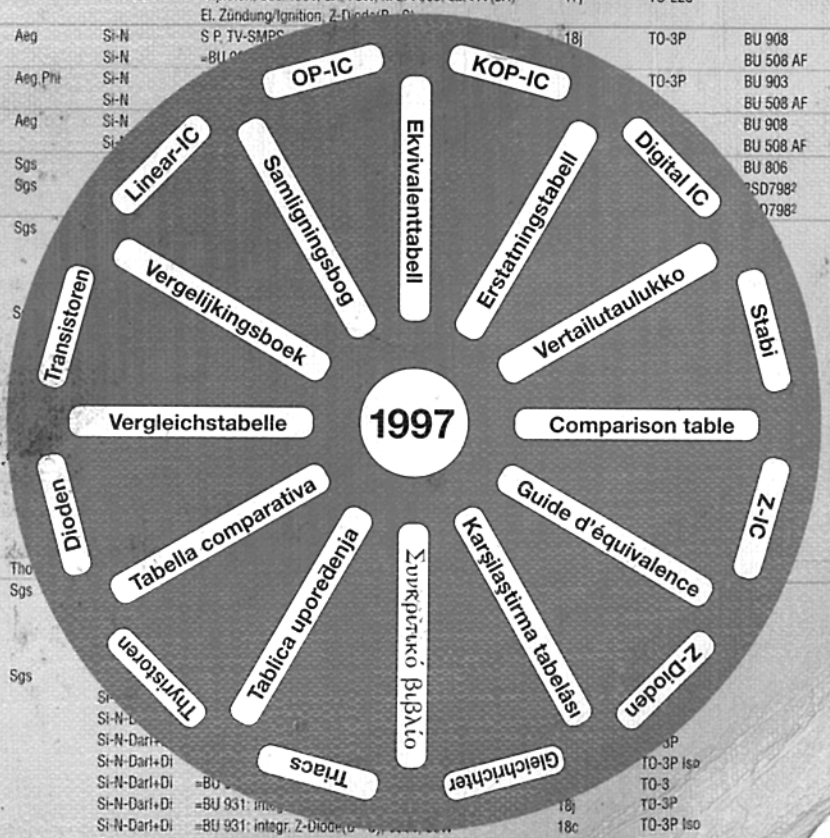
SEMICON 1997

Original	Fabric.	Constr.	Info	Compl.	Fig.	JAEGER	Fig.	International
BUK 427-600A,B	Phi	MOS-N-FET-e	VFET, 600/30V, 45W, 80/275ns(2,8A) A: 4,3/17A, <1Ω(6,5A), B: 3,9/16A, <1,2Ω(6,5A)		16c	SOT-199		BUK 727-600, 2SK1463, 2SK1684, 2SK1859
BUK 428-500A,B	Phi	MOS-N-FET-e	VFET, 500/30V, 45W, 120/410ns(2,9A) A: 6,8/27A, <0,4Ω(8A), B: 6,1/24A, <0,5Ω(8A)		16c	SOT-199		2SK1206, 2SK1523, 2SK1696, 2SK1832
BUK 428-800A,B	Phi	MOS-N-FET-e	VFET, 800/30V, 45W, 160/450ns(2,6A) A: 3,4/14A, <1,5Ω(4A), B: 3/12A, <2Ω(4A)		16c	SOT-199		2SK809A, 2SK1463, 2SK1684, 2SK1859
BUK 428-1000A,B	Phi	MOS-N-FET-e	VFET, 1000/30V, 45W, 160/450ns(2,5A) A: 2,9/12A, <2Ω(3,5A), B: 2,6/10A, <2,6Ω(3,5A)		16c	SOT-199		BUK 426-1000, 2SK1770
BUK 436-50A,B	Phi	MOS-N-FET-e	=BUK 426-50A,B: A=50/200A, B=46/184A, 125W		18p	TO-3P		BUZ 346, 2SK1297, 2SK1379, 2SK1514
BUK 436-60A,B	Phi	MOS-N-FET-e	=BUK 426-60A,B: A=50/200A, B=46/184A, 125W		18p	TO-3P		2SK1297, 2SK1379, 2SK1514, 2SK2096
BUK 436-100A,B	Phi	MOS-N-FET-e	=BUK 426-100A,B: A=33/132A, B=31/124A, 125W		18p	TO-3P		BUZ 345, 2SK850, 2SK906, 2SK1429, ++
BUK 436-200								
BUK 436-800								
BUK 436-100								
BUK 437-400								
BUK 437-450								
BUK 437-500								
BUK 437-600								
BUK 438-500								
BUK 438-800								
BUK 438-100								
BUK 439-60A								
BUK 441-60A								
BUK 441-100								
BUK 442-50A								
BUK 442-60A								
BUK 442-100								
BUK 443-50A								
BUK 443-60A								
BUK 443-100								
BUK 444-200								
BUK 444-400								
BUK 444-450								
BUK 444-500								
BUK 444-600								
BUK 444-800								
BUK 445-50A								
BUK 445-60A								
BUK 445-100								
BUK 445-200								
BUK 445-400								
BUK 445-450								
BUK 445-500								
BUK 445-600								
BUK 446-800								
BUK 446-100								
BUK 451-60A								
BUK 451-100								
BUK 452-50A								
BUK 452-60A								
BUK 452-100								
BUK 45								
BUK 45								
BUK 45								
BUK 454-200								
BUK 454-400								
BUK 454-450								
BUK 454-500								
BUK 454-600								
BUK 454-800								

Original	Fabric.	Constr.	Info	Compl.	Fig.	JAEGER	Fig.	International
KSV 3100 ACN-....	Sam	A/D-D/A-IC	8-Bit A/D- + 10-Bit D/A-Converter		40-DIP			-
KSV 3110(CN-....)	Sam	A/D-D/A-IC	8 Bit A/D- + 10 Bit D/A-Conv., Video, TTL In/Out		40-DIP			-
KSV 3208(CN)	Sam	A/D-IC	8 Bit, hi-speed, TV, Video, 20Msps, TTL In/Out		28-DIP			-
KSV 3310	Sam	D/A-IC	10 Bit, TV, Video, 20MHz		28-DIP			-
KSV 3404	Sam							
KSY 13	Sie							

KT
KT
KT
KT 208(A....V) GUS
KT 209(A....V) GUS
KT 814 A,B,G,V GUS
KT 815 A,B,G,V GUS
KT 816 A,B,G,V GUS
KT 817 A,B,G,V GUS
KT 818 A,B,G,V GUS
KT 819 A,B,G,V GUS
KT 3030 Sam
KT 3031 Sam
KT 3032 Sam
KT 3033 Sam
KT 3040 J Sam
KT 3054 J Sam
KT 3064 J Sam
KT 3107(A....V) GUS
KT 3170 J,N Sam
KT 5116 J Sam
KT 8518 Sam
KT 8520 Sam
KT 8521 Sam
KT 8554(J) Sam
KT 8555(J) Sam
KT 8557(J) Sam
KT 8592(N) Sam
KT 8593(N) Sam
KTA 200 Kec
KTA 473 Kec
KTA 940 Kec
KTA 950 Kec
KTA 968(A) Kec
KTA 1001 Kec
KTA 1015 Kec
KTA 1021 Kec
KTA 1023 Kec
KTA 1024 Kec
KTA 1070 Kec
KTA 1270 Kec
KTA 1271 Kec
KTA 1272 Kec
KTA 1273 Kec
KTA 1274 Kec
KTA 1275 Kec

Original	Fabric.	Constr.	Info	Compl.	Fig.	JAEGER	Fig.	Inter
BU 806	Phi,Sgs,Tx	Si-N-Darl+Di	TV-HA, 400/200V, 8/15A, 60W, sat<1,5V(5A)		17j	TO-220	BU 806	17j
BU 806 AF		Si-N-Darl+Di	=BU 806: Iso		17c			
BU 806 FI	Tho	Si-N-Darl+Di	=BU 806: Iso, 30W		17c	TO-220Iso		
BU 807	Phi,Sgs,Tx	Si-N-Darl+Di	=BU 806: 330/150V		17j	TO-220	BU 806	17j
BU 807 FI	Tho	Si-N-Darl+Di	=BU 807: Iso, 30W		17c	TO-220Iso		
BU 808 DFI [SGS]	Sgs	Si-N-Darl+Di	=BU 808FI: integr. Damper-Diode		18c	TO-3P Iso		
BU 808 FI [SGS]	Sgs	Si-N-Darl	CTV-HA, 1400/700V, 5/10A, 50W, hFE>25,sat<1,6V(5A)		18c	TO-3P Iso		
BU 808 [Philips]	Phi	Si-N	3Ph.-Motor Drv, 1500/700V, 12/20A, 160W,sat<1V(9V)		23a	TO-3		
BU 810	Sgs	Si-N-Darl+Di	S P, 600/400V, 7/10A, 75W, <0,6/2µs, sat<3V(7A)		17j	TO-220	2SD798	17j
BU 824	Phi	Si-N-Darl+Di	S P, 650/375V, 0,5/1A, 12,5W, hFE>325, <1/2,5µs		13h	TO-202		
BU 826	Phi	Si-N-Darl+Di	S P, 800/375V, 6/8A, 125W, <1,3/2,2µs,sat<2,5V(4A)		18j	TO-3P	BU 826	18j
BU 826 A		Si-N-Darl+Di	=BU 826: 1000/400V		18j	TO-3P		
BU 900	Tho	Si-N-Darl	Tripleton, 650/400V, 8A, 70W, hFE>7000, sat<4V(3A) El. Zündung/Ignition, Z-Diode(B...C)		17j	TO-220		
BU 902	Aeg	Si-N	S P, TV-SMPS		18j	TO-3P	BU 908	18j
BU 902 F		Si-N	=BU 9				BU 508 AF	16c
BU 903	Aeg,Phi	Si-N				TO-3P	BU 903	18j
BU 903 F		Si-N					BU 508 AF	16c
BU 908	Aeg	Si-N					BU 908	18j
BU 908 AF		Si-N					BU 508 AF	16c
BU 910	Sgs						BU 806	17j
BU 911	Sgs						2SD798²	17j
BU 912							2SD798²	17j
BU 920	Sgs							
BU 920 P								
BU 920 PFI								
BU 920 T								
BU 921	S							
BU 921 P								
BU 921 PFI								
BU 921 T								
BU 921 ZP								
BU 921 ZPFI								
BU 921 ZT								
BU 921 ZTFI								
BU 922								
BU 922 P								
BU 922 PFI								
BU 922 T								
BU 926	Tho							18j
BU 930	Sgs							
BU 930 P								
BU 930 Z								
BU 930 ZP								
BU 931	Sgs							
BU 931 P								
BU 931 PFI								
BU 931 RPFI		Si-N-Darl+Di					TO-3P Iso	
BU 931 Z		Si-N-Darl+Di	=BU				TO-3	
BU 931 ZP		Si-N-Darl+Di	=BU 931:		18j		TO-3P	
BU 931 ZPFI		Si-N-Darl+Di	=BU 931: integr. Z-Diode(B...C)		18c		TO-3P Iso	
BU 932	Sgs	Si-N-Darl+Di	=BU 930: 500/450V		23a		TO-3	
BU 932 P		Si-N-Darl+Di	=BU 932: 105W		18j		TO-3P	



80.000 types

Original	Fabric.	Constr.	Info	{Compl. Fig.		JAEGER	Fig.	International
AUY 14	Sie	Ge-P	LF P, 65V, 10A, 36,5W	23a	TO-41			AUY 21, 2N2289, 2N2292
AUY 15	Sie	Ge-P	LF P, 65V, 10A, 36,5W	23a	TO-41			AUY 21, 2N2289, 2N2292
AUY 16	Sie	Ge-P	LF P, 80V, 8A, 36,5W	23a	TO-41			AUY 22, 2N2289, 2N2292
AUY 17	Sie	Ge-P	LF P, 80V, 8A, 36,5W	23a	TO-41			AUY 22, 2N2289, 2N2292
AUY 18	Gpd,Sgs,Sie	Ge-P	LF,S P, 64V, 8A, 11W	2a	TO-8			AUY 35, AUY 36
AUY 19	Gpd,Sgs,Sie	Ge-P	LF,S P, 64V, 3A, 30W	23a	TO-3	AL 102	23a	AL 102, AUY 20, 2N1531/36, 2N1541/46
AUY 20	Gpd,Sgs,Sie	Ge-P	=AUY 19: 80V	23a	TO-3	AL 102	23a	AL 102, AUY 28, 2N1531/36, 2N1541/46
AUY 21	Gpd,Sgs,Sie	Ge-P	LF,S P, 65V, 10A, 36W	23a	TO-3, -41	(AL 102)[7]	23a	ASZ 16, ASZ 17, 2N2526, 2N2289, 2N2292
AUY 22	Gpd,Sgs,Sie	Ge-P	LF,S P, 80V, 8A, 36W	23a	TO-3, -41	AL 102	23a	ASZ 15, ASZ 18, 2N2526, 2N2289, 2N2292
AUY 24	Gpd,Sie	Ge-P	LF P, 65V, 3A, 30W	23a	TO-41			AL 102, AUY 19, 2N1530/35, 2N1540/45
AUY 26	Gpd,Sie	Ge-P	LF P, 80V, 3A, 30W	23a	TO-41			AL 102, AUY 20, 2N1531/36, 2N1541/46
AUY 27	Gpd,Sie	Ge-P	LF P, 80V, 3A, 30W	23a	TO-41			AL 102, AUY 20, 2N1531/36, 2N1541/46
AUY 28	Aeg,Gpd	Ge-P	LF,S P, 90V, 6A, 30W	23a	TO-3			AL 102, ASZ 15, ASZ 18, 2N3616/18
AUY 29	Gpd,Sie	Ge-P	LF,S P, 50V, 15A, 36W	23a	TO-41			2N1549...1560
AUY 30	Tho	Ge-P	LF,S P, 100V, 10A, 33W	23a	TO-3			AUY 37, 2N2527, 2N2290, 2N2293
AUY 31	Tho	Ge-P	LF,S P, 60V, 6A, 33W	23a	TO-3			AL 102, ASZ 16...17, AUY 21, 2N3612/14
AUY 32	old	Ge-P	LF,S P, 80V, 3A, 33W	23a	TO-3			AL 102, AUY 20, 2N2141/46
AUY 33	old	Ge-P	=AUY 33: 60V	23a	TO-3			AL 102, AUY 19, 2N2139/44
AUY 34	Gpd,Sie	Ge-P	LF,S P, 100V, 3A, 30W	23a	TO-3			AL 102, AUY 28, 2N1532/37, 2N1542/47
AUY 35	Sgs	Ge-P	LF,S P, 70V, 10A, 15W	2a	TO-8			AUY 36
AUY 36	Sgs	Ge-P	LF,S P, 70V, 10A, 15W	2a	TO-8			AUY 35
AUY 37	Sgs	Ge-P	LF,S P, 100V, 10A, 30W	23a	TO-3			2N2527, 2N2290, 2N2293
AUY 38	Sgs	Ge-P	S P, 130V, 10A, 30W	23a	TO-3			AL 100, 2N2528
AUZ 11(D)	Aeg	Ge-P	LF,S P, 50V, 1A, 6W					(AD 162, AUY 18)[4]
AV		Si-P	=2SB804-AV (SMD-Marking)	39	SOT-89			›2SB804
AV 03-03....-30	Hit	Z-Di	3....30V, ±5%, 10W	32a	DO-4			BZX 98/..., BZY 93/..., 1N2970...89
AVS 08 ...	Tho	LIN-IC+Triac	Control IC+Triac(±500V, 5A≈)f.SMPS<200W, 110/220V≈	8-DIP+17I	+TO-220			-
AVS 10 ...	Tho	LIN-IC+Triac	Control IC+Triac(±600V, 8A≈)f.SMPS<300W, 110/220V≈	8-DIP+17I	+TO-220			-
AVS 12 ...	Tho	LIN-IC+Triac	Control IC+Triac(±600V, 12A≈)f.SMPS<500W,110/220V≈	8-DIP+17I	+TO-220			-
AVS 20 ...	Tho	LIN-IC+Triac	Control IC+Triac(±600V, 8A≈)f.SMPS<300W,120/230V≈	8-DIP+17I	+TO-220			-
AVS 200 ...	Tho	LIN-IC+Triac	Control IC+Triac(±800V, 8A≈)f.SMPS<300W,120/230V≈	8-DIP+17I	+TO-220			-
AVS 08...200 ...I		LIN-IC+Triac	Iso	17I	TO-220 Iso			-
AW		Si-P	=2SB804-AW (SMD-Marking)	39	SOT-89			›2SB804
AW		Si-N	=BCX 70RH (SMD-Marking)	35	SOT-23			›BCX 70RH
AW 01-06...-33	Hit	Z-Di	6....33V, ±5%, 1W	31a	SOD-57	Z-Diode V	31a	BZV 85/..., BZW 22/..., BZX 61/..., ZPY...,+
AW 03-02....-05	Hit	Si-St	0,26A, 1W, Uf=1,4....5,4V	31a	SOD-51	(Z-Diode ....V)	31a	-
AX		Si-P	=2SA1739 (SMD-Marking)	35(2mm)	SOT-323			›2SA1739
AX		Si-N	=BCX 70RJ (SMD-Marking)	35	SOT-23			›BCX 70RJ
AX		Si-N+R	=XN 2212 (SMD-Marking)	45	SOT-153			›XN 2212
AXQ		Si-P	=2SA1739-Q (SMD-Marking)	35	SOT-23			›2SA1739
AXR		Si-P	=2SA1739-R (SMD-Marking)	35	SOT-23			›2SA1739
AY....AZ								
AY		Si-N	=2SC2880-Y (SMD-Marking)	39	SOT-89			›2SC2880
AY		Si-N	=2SC3392 (SMD-Marking)	35	SOT-23			›2SC3392
AY		Si-N	=2SC4210-Y (SMD-Marking)	35	SOT-23			›2SC4210
AY		Si-N	=BCX 70RK (SMD-Marking)	35	SOT-23			›BCX 70RK
AY		Si-N	=KTC4372-Y (SMD-Marking)	39	SOT-89			›KTC 4372
AY-3-1232	Gie	LIN-IC	Digitaluhr/Digital Clock					-
AY-3-8203	Gie	LIN-IC	US-FB, Decoder	40-DIP				-
AY-3-8210	Gie	LIN-IC						-
AY-3-8500	Gie	LIN-IC	TV, Spielemodul/Game Module					-
AY-3-8610	Gie	LIN-IC						-
AY-3-8765	Gie	LIN-IC						
AY-3-9900	Fer	LIN-IC	Telefon, CODEC, TTL compatible	24-DIP				ZNPCM 1
AY-5-1203A	Gie	LIN-IC	TV, Kanal-Nr.-Einblendung/Channel No. fade-in	28-DIP				-
AY-5-8320	Gie	LIN-IC	TV, Kanal-Nr.-Einblendung/Channel No. fade-in	24-DIP				-
AY-5-8322	Gie	LIN-IC	Digitaluhr/Digital Clock					-
AY 101	Tho	Ge-Di	TV-Booster-Di, 150V, 15A(ss)	(32a)				-
AY 102	Sgs	Ge-Di	TV-Booster-Di, 60/320V, 7A	23j	TO-3			-
AY 103 K	Sgs	Ge-Di	TV-Booster-Di, 60/320V, 7A	3	TO-1°			-
AY 104	Sgs	Ge-Di	S, 90V, 5A(ss)	4	TO-1			-
AY 105 K	Sgs	Ge-Di	TV-Booster-Di, 80/250V, 5A(ss)	3	TO-1°			-
AY 106	Sgs	Ge-Di	TV-Booster-Di, 60/200V, 7A	23j	TO-3			-
AZ		Si-N	=BCX 70RL (SMD-Marking)	35	SOT-23			›BCX 70RL
AZO		Si-P	=KTA1505-O (SMD-Marking)	35	SOT-23			›KTA 1505
AZY		Si-P	=KTA1505-Y (SMD-Marking)	35	SOT-23			›KTA 1505
B								
B....	JAP	...-P	›2SB...., z.B./e.g. "B861" = 2SB861 ›	Japantypen				
B....	Sam	...-P	›KSB...., z.B./e.g. "B1116"=KSB1116 ›	Samsung				
B		N-FET	=2SK1068 (SMD-Marking)	35(2mm)	SOT-323			›2SK1068
B		GaAs-FET	=2SK1325 (Marking)	52	=SOT-100			›2SK1325
B		GaAs-N-FET	=2SK1616 (Marking)	52	=SOT-100			›2SK1616
B		Si-Di	=MA 2S728 (SMD-Marking)	71(1,7mm)	SOD-323			›MA 728
B 1		MOS-N-FET-e	=2SK1824 (SMD-Marking)	35(1,6mm)	SS Mini			›2SK1824
B 1		Si-P	=D71G.05T1 (SMD-Marking)	39	SOT-89			›D71G.05T1
B 1		Si-Di	=HSM 2692 (SMD-Marking)	35	SOT-23			›HSM 2692
B 1 O		Si-N	=KSC 2715-O (SMD-Marking)	35	SOT-23			›KSC 2715
B 1 R		Si-N	=KSC 2715-R (SMD-Marking)	35	SOT-23			›KSC 2715
B 1 Y		Si-N	=KSC 2715-Y (SMD-Marking)	35	SOT-23			›KSC 2715
B 2		Si-N	=2SC1621-B2 (SMD-Marking)	35	SOT-23			›2SC1621
B 2		Si-N	=2SC4175-B2 (SMD-Marking)	35(2mm)	SOT-323			›2SC4175
B 2(p)		Si-N	=BSV 52 (SMD-Marking)	35	SOT-23			›BSV 52
B 03A-1B....		Si-Br				B250C1500	8	B....C300
B 3		Si-Di	=1SS184 (SMD-Marking)	35	SOT-23			›1SS184
B 3		Si-Di	=1SS301 (SMD-Marking)	35(2mm)	SOT-323			›1SS301
B 3		Si-Di	=1SS361 (SMD-Marking)	35(1,6mm)	SS Mini			›1SS361
B 3		Si-N	=2SC1621-B3 (SMD-Marking)	35	SOT-23			›2SC1621
B 3		Si-N	=2SC4175-B3 (SMD-Marking)	35(2mm)	SOT-323			›2SC4175
B 3		Si-Di	=HSM 2694 (SMD-Marking)	35	SOT-23			›HSM 2694
B 3 T		Si-Di	=1PS184 (SMD-Marking)	35	SOT-23			›1PS184

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
B 4		Si-N	=2SC1621-B4 (SMD-Marking)		35	SOT-23			›2SC1621
B 4		Si-N	=2SC4175-B4 (SMD-Marking)		35(2mm)	SOT-323			›2SC4175
B 4		Si-N	=BSV 52R (SMD-Marking)		35	SOT-23			›BSV 52R
B 4		Si-Di	=HSM 2693A (SMD-Marking)		35	SOT-23			›HSM 2693A
B 5(p)		Si-P	=BSR 12 (SMD-Marking)		35	SOT-23			›BSR 12
B 6		Si-P	=2SB815-6 (SMD-Marking)		35	SOT-23			›2SB815
B 7		Si-P	=2SB815-7 (SMD-Marking)		35	SOT-23			›2SB815
B 8		Si-P	=BSR 12R (SMD-Marking)		35	SOT-23			›BSR 12R
B 9		Si-Di	=1SS311 (SMD-Marking)		35	SOT-23			›1SS311
B 10		N-FET	=2SK545-B10 (SMD-Marking)		35	SOT-23			›2SK545
B 11		N-FET	=2SK545-B11 (SMD-Marking)		35	SOT-23			›2SK545
B 12		N-FET	=2SK545-B12 (SMD-Marking)		35	SOT-23			›2SK545
B 12		Si-N	=2SC3739-B12 (SMD-Marking)		35	SOT-23			›2SC3739
B 12		Si-N	=2SC4173-B12 (SMD-Marking)		35(2mm)	SOT-323			›2SC4173
B 13		Si-N	=2SC3739-B13 (SMD-Marking)		35	SOT-23			›2SC3739
B 13		Si-N	=2SC4173-B13 (SMD-Marking)		35(2mm)	SOT-323			›2SC4173
B 14		Si-N	=2SC3739-B14 (SMD-Marking)		35	SOT-23			›2SC3739
B 14		Si-N	=2SC4173-B14 (SMD-Marking)		35(2mm)	SOT-323			›2SC4173
B 15		Si-N	=NTM 2222A (SMD-Marking)		35	SOT-23			›NTM 2222A
B 22		Si-N	=2SC3734-B22 (SMD-Marking)		35	SOT-23			›2SC3734
B 23		Si-N	=2SC3734-B23 (SMD-Marking)		35	SOT-23			›2SC3734
B 24		Si-N	=2SC3734-B24 (SMD-Marking)		35	SOT-23			›2SC3734
B 25		Si-N	=NTM 3904 (SMD-Marking)		35	SOT-23			›NTM 3904
B 26		Si-N	=BF 570 (SMD-Marking)		35	SOT-23			›BF 570
B 33		Si-N	=2SC3735-B33 (SMD-Marking)		35	SOT-23			›2SC3735
B 33		Si-N	=2SC4176-B33 (SMD-Marking)		35(2mm)	SOT-323			›2SC4176
B 34		Si-N	=2SC3735-B34 (SMD-Marking)		35	SOT-23			›2SC3735
B 34		Si-N	=2SC4176-B34 (SMD-Marking)		35(2mm)	SOT-323			›2SC4176
B 35		Si-N	=2SC3735-B35 (SMD-Marking)		35	SOT-23			›2SC3735
B 35		Si-N	=2SC4176-B35 (SMD-Marking)		35(2mm)	SOT-323			›2SC4176
B 51		Si-N	=2SB736A-B51(SMD-Marking)		35	SOT-23			›2SB736A
B 52		Si-N	=2SB736A-B52(SMD-Marking)		35	SOT-23			›2SB736A
B 53		Si-N	=2SB736A-B53(SMD-Marking)		35	SOT-23			›2SB736A
B 54		Si-N	=2SB736A-B54(SMD-Marking)		35	SOT-23			›2SB736A
B 55		Si-N	=2SB736A-B55(SMD-Marking)		35	SOT-23			›2SB736A
B 060 D	Hfo	OP-IC	›TL 060		8-DIP				›TL 060
B 060 SD,SG	Hfo	OP-IC	=B 060D: SMD, SD=-10…+70°, SG=-25…+85°		8-MDIP				›TL 060
B 061 D	Hfo	OP-IC	›TL 061		8-DIP				›TL 061
B 061 SD,SG	Hfo	OP-IC	=B 061D: SMD, SD=-10…+70°, SG=-25…+85°		8-MDIP				›TL 061
B 062 D	Hfo	OP-IC	›TL 062		8-DIP				›TL 062
B 062 SD,SG	Hfo	OP-IC	=B 062D: SMD, SD=-10…+70°, SG=-25…+85°		8-MDIP				›TL 062
B 064 D	Hfo	OP-IC	›TL 064		14-DIP				›TL 064
B 064 SD,SG	Hfo	OP-IC	=B 064D: SMD, SD=-10…+70°, SG=-25…+85°		14-MDIP				›TL 064
B 066 D	Hfo	OP-IC	›TL 066		8-DIP				›TL 066
B 066 SD,SG	Hfo	OP-IC	=B 066D: SMD, SD=-10…+70°, SG=-25…+85°		8-MDIP				›TL 066
B 080 D	Hfo	OP-IC	›TL 080		8-DIP				›TL 080
B 81		Si-P	=BSR 12R (SMD-Marking)		35	SOT-23			›BSR 12R
B 081 D	Hfo	OP-IC	›TL 081		8-DIP				›TL 081
B 082 D	Hfo	OP-IC	›TL 082		8-DIP				›TL 082
B 083 D	Hfo	OP-IC	›TL 083		14-DIP				›TL 083
B 084 D	Hfo	OP-IC	›TL 084		14-DIP				›TL 084
B 109 C,D	Hfo	OP-IC	=A 109D: verbessert/improved,-25…+85°		14-DIC/DIP				… 709…, … 1709…
B 110 C,D	Hfo	KOP-IC	=A 110D: verbessert/improved,-25…+85°		14-DIC/DIP				… 710…, … 1710…
B 165 H,V	Hfo	OP-IC	›L 165		17/5Pin	TO-220/5			›L 165
B 176 D	Hfo	OP-IC	›µA 776		8-DIP				›µA 776
B 177 D	Hfo	OP-IC	=B 176D		14-DIP				›B 176
B 211		Ge-Di	=2x AA 119				2x AA 119	31a	›AA 119
B 222 D	Hfo	LIN-IC	Doppelgegentaktmischer/Dual-PP-Mixer		14-DIP				-
B 260 D	Hfo	LIN-IC	TV, SMPS Controller		16-DIP		TDA 1060(B)	16-DIP	NE 5560, SE 5560, TDA 1060
B 290 SD	Hfo	LIN-IC	=A 290D: SMD		14-MDIP				-
B 303 D	Hfo	LIN-IC	Näherungsschalter/Proximity Detector		14-DIP				-
B 303 SF	Hfo	LIN-IC	=A 303D: SMD		14-MDIP				-
B 304 D	Hfo	LIN-IC	Näherungsschalter/Proximity Detector		14-DIP				-
B 304 SF	Hfo	LIN-IC	=A 304D: SMD		14-MDIP				-
B 305 D	Hfo	LIN-IC	Näherungsschalter/Proximity Detector		14-DIP				-
B 305 SF	Hfo	LIN-IC	=A 305D: SMD		14-MDIP				-
B 306 D	Hfo	LIN-IC	Näherungsschalter/Proximitiy Detector		8-DIP				-
B 306 SF	Hfo	LIN-IC	=A 306D: SMD		8-MDIP				-
B 308 D	Hfo	LIN-IC	Telefonverstärker/Telephone Amp.		14-DIP				(TBA 830)
B 315 D	Hfo	LIN-IC	4x NPN Transistor Array, 20V, 0,5A		14-DIP				(Q 2 T2222)
B 315 E	Hfo	LIN-IC	=B 315D: Fig. ›		14-DIP+a				-
B 315 K	Hfo	LIN-IC	=B 315D: Fig. ›		14-DIP+a°				-
B 318 D	Hfo	LIN-IC	Telefonverstärker/Telephone Amp.		14-DIP				-
B 325 D	Hfo	LIN-IC	=B 315D: 30V		14-DIP				(Q 2 T2222)
B 325 E	Hfo	LIN-IC	=B 315D: 30V		14-DIP+a				-
B 325 K	Hfo	LIN-IC	=B 315D: 30V		14-DIP+a°				-
B 331 G	Hfo	LIN-IC	Hörgeräteverst./Hearing Aid Amp.		14-FLP				-
B 340 D	Hfo	LIN-IC	4x NPN Transistor Array, 20V, 10mA		14-DIP				-
B 341 D	Hfo	LIN-IC	4x NPN Transistor Array, 20V, 10mA		14-DIP				-
B 342 D	Hfo	LIN-IC	4x NPN Transistor Array, 20V, 10mA		14-DIP				-
B 360 D	Hfo	LIN-IC	=B 315D: 90V		14-DIP				(TPQ 2222, TPQ 3724)
B 360 E	Hfo	LIN-IC	=B 315D: 90V		14-DIP+a				-
B 360 K	Hfo	LIN-IC	=B 315D: 90V		14-DIP+a°				-
B 380 D	Hfo	LIN-IC	=B 315D: 100V		14-DIP				(TPQ 2222, TPQ 3725)
B 380 E	Hfo	LIN-IC	=B 315D: 100V		14-DIP+a				-
B 380 K	Hfo	LIN-IC	=B 315D: 100V		14-DIP+a°				-
B 384 D	Hfo	LIN-IC	Telecom, Telefonspg.-Versorg./Telephone PS		20-DIP				-
B 385 D	Hfo	LIN-IC	Telecom, Telefontestkreis/Telephone Test Circuit		16-DIP				-
B 386 D	Hfo	LIN-IC	Telecom, Telefonspeisekreis/Supply Circuit		20-DIP				-
B 390 D	Hfo	LIN-IC	Motorregler/Motor Control		18-DIP				-
B 391 D	Hfo	LIN-IC	Recorder, Motor Processor		18-DIP				-
B 411 DD	Hfo	OP-IC	FET Inp, ±18V, -10…+70°		8-DIP				LF 411 ACN
B 451 G	Hfo	LIN-IC	Hall-IC, Ucc=4,75…27V		8-SIP				SAS 251

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
B 452 G	Hfo	LIN-IC	Hall-IC, Ucc=4,75…18V		8-SIP				S 251S5
B 453 G	Hfo	LIN-IC	Hall-IC, Ucc=4,75…5,25V		8-SIP				SAS 251S4
B 460 G	Hfo	LIN-IC	Hall-IC, Ucc=4,75…18V		8-SIP				-
B 461 G	Hfo	LIN-IC	Hall-IC, Sensor, Ucc=4,75…5,25V		4-SIP				SAS 261S4
B 462 G	Hfo	LIN-IC	=B 461: Ucc= 4,75…18V		4-SIP				SAS 261
B 466 GA	Hfo	LIN-IC	Hall-IC, Ucc=0,5…14,5V		8-SIP				-
B 467 GE	Hfo	LIN-IC	Hall-IC, Ucc=4,5…28		4-SIP				-
(SSi)B 0510….0580	Sie	Si-Di	›SSi B 0510…0580		27c		BY 255	31a	
B 511 N	Hfo	LIN-IC	Temperature Sensor		7				-
B 555 D	Hfo	LIN-IC	›NE 555N		8-DIP		NE 555 N	8-DIP	›NE 555N
B 556 D	Hfo	LIN-IC	›NE 556N		14-DIP		NE 556 N	14-DIP	›NE 556N
B 584 X	Hfo	LIN-IC	Spg.-/Voltage Reference, 10+7,5+5+2,5V						AD 584
B 589 N	Hfo	LIN-IC	Ref.-Spg.-Quelle/Voltage Reference, 1,235V		7				AD 589
B 611 D	Hfo	OP-IC	›TCA 311A		6-DIP				›TCA 311A
B 615 D	Hfo	OP-IC	›TCA 315A		6-DIP				›TCA 315A
B 621 D	Hfo	OP-IC	›TCA 321A		6-DIP				›TCA 321A
B 621 SC	Hfo	OP-IC	=B 621D: SMD		8-MDIP				-
B 625 D	Hfo	OP-IC	›TCA 325A		6-DIP				›TCA 325A
B 625 SG	Hfo	OP-IC	=B 625D: SMD		8-MDIP				-
B 631 D	Hfo	OP-IC	›TCA 331A		6-DIP				›TCA 331A
B 635 D	Hfo	OP-IC	›TCA 335A		6-DIP				›TCA 335A
B 654 D	Hfo	LIN-IC	Servomotor Controller		14-DIP				SN 28654
B 761 D	Hfo	OP-IC	›TAA 761A		6-DIP				›TAA 761A
B 761 SC	Hfo	OP-IC	=B 761D: SMD		8-MDIP				-
B 765 D	Hfo	OP-IC	›TAA 765A		6-DIP				›TAA 765A
B 765 SG	Hfo	OP-IC	=B 765D: SMD		8-MDIP				-
(SSi)B 0810….0880	Sie	Si-Di	›SSi B 0810…0880		31a	DO-27	BA 159	31a	
B 861 D	Hfo	OP-IC	›TAA 861A		6-DIP				›TAA 861A
B 861 SC	Hfo	OP-IC	=B 861D: SMD		8-MDIP				-
B 865 D	Hfo	OP-IC	›TAA 865A		6-DIP				›TAA 865
B 865 SG	Hfo	OP-IC	=B 865D: SMD		8-MDIP				-
B 1085		Ge-P	TV-HA		23a	TO-3			AU 106, AU 109, AU 111, AU 112, 2N5325
B 2510 B	Sie	Si-Di	›SSi B 2510…2580				SKE 4F2/10	33a	
B 2600 DG	Hfo	LIN-IC	SMPS Controller		18-DIP				-
B 2761 D	Hfo	OP-IC	›TAA 2761A		8-DIP				›TAA 2761A
B 2761 SC	Hfo	OP-IC	=B 2761D: SMD		8-MDIP				-
B 2765 D	Hfo	OP-IC	›TAA 2765A		8-DIP				›TAA 2765A
B 2765 S	Hfo	OP-IC	=B 2765D: SMD						-
B 2765 SG	Hfo	OP-IC	=B 2765D: SMD		8-MDIP				-
B 2960 VG	Hfo	LIN-IC	DC-DC Schaltregler/Switching Regulator		15-SQL				L 296
B 3040 DA	Hfo	LIN-IC	Treiber-Sensor-Kombi/Driver Sensor IC		28-DIP				-
B 3170 V	Hfo	Z-IC	›LM 317		17l	TO-220			LM 317T
B 3171 V	Hfo	Z-IC	›LM 317: +1,2…+57V		17l	TO-220			-
B 3370 V	Hfo	Z-IC	›LM 337		17n	TO-220			LM 337T
B 3371 V	Hfo	Z-IC	›LM 337: -1,2…-47V		17n	TO-220			-
B 3718 VC	Hfo	LIN-IC	Stepper Motor Controller, 45V, ±1,5A		15-SQL				TEA 3718SP
B 3870 D	Hfo	LIN-IC	Telecom, NF-Schaltung/Audio Circuit		28-DIP				-
B 3925 DD	Hfo	LIN-IC	Motor Processor f. Floppy-Disk (FDD)		20-DIP				-
B 4002 D	Hfo	LIN-IC	Endstufentreiber/Power Output Driver		16-DIP				UAA 4002DP
B 4211 D	Hfo	LIN-IC	Motorregler/Motor Speed Control						U 211B
B 4761 D	Hfo	OP-IC	›TAA 4761A		14-DIP				›TAA 4761A
B 4765 D	Hfo	OP-IC	›TAA 4765A		14-DIP				›TAA 4765A
B 5000		Si-N	LF/HF-Drv,Out, 35V, 3A, 25W(Tc=100°), 3MHz						-
B 7240 X	Hfo	LIN-IC	12-Bit Stromquelle/Current Source						-
BA									
BA		Si-N	=µPA500T (SMD-Marking)		45	SOT-153			›µPA500T
BA		Si-N/P	=µPA674T (SMD-Marking)		46(2mm)	SOT-363			›µPA674T
BA		Si-Di	=1SS154 (SMD-Marking)		35	SOT-23			›1SS154
BA		Si-P	=2SB1118 (SMD-Marking)		39	SOT-89			›2SB1118
BA		Si-P	=2SB1132 (SMD-Marking)		39	SOT-89			›2SB1132
BA		Si-N	=2SD1367-BA (SMD-Marking)		39	SOT-89			›2SD1367
BA		Si-N	=BCP 54 (SMD-Marking)		=39°	SOT-223			›BCP 54
BA(p,s)		Si-P	=BCW 61A (SMD-Marking)		35	SOT-23			›BCW 61A
BA		Si-N	=BCX 54 (SMD-Marking)		39	SOT-89			›BCX 54
BA-S200	Rhm	LIN-IC	Universal Building Block		24-DIC				-
BA		Si-N+R	=XN 2216 (SMD-Marking)		45	SOT-153			›XN 2216
BA		Si-N	=µPA570T (SMD-Marking)		45(2mm)	SOT-353			›µPA570T
BA 1 A3Q…L4Z	Nec	Si-N+R	=AA 1A3Q…L4Z:	{BN1…	40c	(SST)			-
BA 2 A3Q	Nec	Si-N+R	S, Rb=1k, Rbe=10kΩ, 60/50V, 0,1/0,2A, 0,25W hi-hFE>300	{BN2A3Q	40c	(SST)			-
BA 2 A4M	Nec	Si-N+R	=BA 2A3Q: Rb=10k, Rbe=10kΩ, hi-hFE>300	{BN2A4M	40c	(SST)			-
BA 2 A4P	Nec	Si-N+R	=BA 2A3Q: Rb=10k, Rbe=47kΩ, hi-hFE>550	{BN2A4P	40c	(SST)			-
BA 2 A4Z	Nec	Si-N+R	=BA 2A3Q: Rb=10k, Rbe=-, hi-hFE>700	{BN2A4Z	40c	(SST)			-
BA 2 F4M	Nec	Si-N+R	=BA 2A3Q: Rb=22k, Rbe=22kΩ, hi-hFE>450	{BN2F4M	40c	(SST)			-
BA 2 F4N	Nec	Si-N+R	=BA 2A3Q: Rb=22k, Rbe=47kΩ, hi-hFE>550	{BN2F4N	40c	(SST)			-
BA 2 F4Z	Nec	Si-N+R	=BA 2A3Q: Rb=22k, Rbe=-, hi-hFE>700	{BN2F4Z	40c	(SST)			-
BA 2 L3M	Nec	Si-N+R	=BA 2A3Q: Rb=Rbe=4,7kΩ, hi-hFE>200	{BN2L3M	40c	(SST)			-
BA 2 L3N	Nec	Si-N+R	=BA 2A3Q: Rb=4,7k, Rbe=10kΩ, hi-hFE>300	{BN2L3N	40c	(SST)			-
BA 2 L3Z	Nec	Si-N+R	=BA 2A3Q: Rb=4,7k, Rbe=-, hi-hFE>700	{BN2L3Z	40c	(SST)			-
BA 2 L4L	Nec	Si-N+R	=BA 2A3Q: Rb=47k, Rbe=22kΩ, hi-hFE>450	{BN2L4L	40c	(SST)			-
BA 2 L4M	Nec	Si-N+R	=BA 2A3Q: Rb=47k, Rbe=47kΩ, hi-hFE>550	{BN2L4M	40c	(SST)			-
BA 2 L4Z	Nec	Si-N+R	=BA 2A3Q: Rb=47k, Rbe=-, hi-hFE>700	{BN2L4Z	40c	(SST)			-
BA 3 L4Z	Nec	Si-N+R	Rb=47kΩ, int. Emitter-Di, 30/20V, 20mA, 0,25W	{BN3L4Z	40c	(SST)			-
BA 100	Phi,Tix	Si-Di	Uni, 60V, 90/100mA, Uf<1,5V(30mA)		31a	DO-7	1N4148	31a	BA 128, 1N4148, 1N5194…5196, ++
BA 101(A,B,C)	Aeg	C-Di	VHF AFC, 25V, 8…25pF/32…55pF(10/1V), <3Ω(30MHz)		31a	DO-7			BB 119, 1SV114, 1SV125, 1SV145…146
BA 102/A…D	Phi,Tho	C-Di	VHF AFC, 20V, 20…45pF/16pF(4/20V), <3Ω(500kHz)		31a	DO-7			BB 119, 1SV114, 1SV125, 1SV145…146
BA 103	Sie	Si-Di	Uni, 6/6V, 0,2/0,3A, Uf<1V(0,1A)		2c	=TO-1	1N4148	31a	BA 127, BA 187…188, BA 215, 1N4148, ++
BA 104	Sie	Si-Di	Uni, 100/100V, 0,19/0,26A, Uf<1,1V(0,1A)		2c	=TO-1	BA 159	31a	BA 188…190, BAY 73, BAY 19…21, ++
BA 105	Sie	Si-Di	Uni, 300/300V, 0,15/0,23A, Uf<1,1V(0,1A)		2c	=TO-1	BA 159	31a	BA 147/300, BAY 21, BAY 46, BAY 88, ++
BA 108	Sie	Si-Di	Uni, 50/50V, 0,19/0,26A, Uf<1,1V(0,1A)		2c	=TO-1	1N4148	31a	BA 127, BA 188…190, BA 215, 1N4148, ++
BA 109	Phi	C-Di	VHF AFC, 20V, 15…54pF(4V)		31a	DO-7			BB 119, 1SV114, 1SV125, 1SV145…146

Original	Fabric.	Constr.	Info {Compl.	Fig.		JAEGER	Fig.	International
BA 110	Itt	C-Di	FM/VHF AFC, 30V, 8…12pF/6,3pF(2/10V), 1Ω(30MHz)	31a	DO-7			BA 111, BA 124, 1S2790, 1SV50
BA 110 G	Itt	C-Di	FM/VHF Tuning, 30V, 10…16pF(2V)	31a	DO-7			BB 109, BB 143, MV 109, 1SV50
BA 111	Aeg,Itt,Tho	C-Di	VHF AFC, 20V, 45…65pF/35pF(2/10V), 0,5Ω(30MHz)	31a	DO-7			BB 119, 1SV114, 1SV125, 1SV145…146
BA 112	Itt	C-Di	AFC, 20V, 80…120pF/63pF(2/10V), 0.5Ω(30MHz)	31a	DO-7			(BA 111, BA 124)
BA 113	Itt	C-Di	AFC, 1400pF/2000pF(2/0,2V)					-
BA 114	Phi	Si-St	9V, 20mA, 0.4W, Uf=0,58…0,8V(3mA)	31a	DO-7	1N4148	31a	BA 216, BA 314, BA 315, 1N4148, ++
BA 115	Phi	Si-Di	S, 150V, 2mA, Uf<3V(10mA)	31a	DO-7	BA 159	31a	BA 195, BAY 80, BAV 20, 1N3070, ++
BA 116	Aei	Si-Di	Dual, TV-AGC, 20/50V, 10/30mA, Uf<1V(10mA)	2h				-
BA 117	Sie	Si-St	6V, 0.2A, 0,26W, Uf=0,72V(1mA), 0,87V(10mA)	31a	DO-7	1N4148	31a	BA 220, BZV49/C0V8, 1N4148, ++
BA 119	Sie	C-Di	FM AFC, 50V, 45…65pF(2V), 1Ω(30MHz)	31a	DO-7			BA 111, BA 124, 1S2790, 1SV50
BA 120	Sie	C-Di	VHF AFC, 50V, 8…12pF(2V), 1,2Ω(30MHz)	31a	DO-7			BB 119, 1SV114, 1SV 125, 1SV145…146
BA 121	Aeg	C-Di	VHF/UHF AFC, 30V, 8…12pF/3,5…4,4pF(2/30V), <2Ω	31a	DO-7			BB 117, BB 417, 1SV89
BA 122	Phi	Si-Di	Uni, 100V, 90mA, Uf<1V(1mA)	31a		BA 159	31a	BA 147/100, 1N5195, 1N5606, ++
BA 123	Itt	C-Di	TV, HA AFC, 11V, 1600…2400pF/580pF(2/11V)	34a	DO-13			-
BA 124/50…65	Aeg	C-Di	FM/VHF AFC, 30V, 44…66pF/20…28pF(2/30V), 0,5Ω	31a	DO-7			BA 111, 1S2790, 1SV50
BA 125/35…50	Aeg,Tho	C-Di	VHF AFC, 30V, 29…51pF(2V), 0.5Ω(30MHz)	31a	DO-7			BB 119, 1SV114, 1SV125, 1SV 145…146
BA 126	Aei	Si-Di	Dual, TV, HA-Diskr., 50/75V, 50/350mA, Uf<2V(10mA)					-
BA 127(D)	Sie,Tix	Si-Di	Uni, 60/60V, 0,2A, Uf<1,1V(0,1A) {D=DO-35	31a	DO-7	1N4148	31a	BA 188…190, BA 215, BAY 45, 1N4148, ++
BA 128	Fch,Sgs,Tix	Si-Di	Uni, 50/75V, 0,11/0,225A, Uf=0,73…1V(50mA)	31a	DO-7	1N4148	31a	BA 127, BA 147/50, BA 187…190, 1N4148++
BA 129	Fch,Sgs,Tix	Si-Di	Uni, 180/200V, 0,225/0,45A, Uf=0,78…1V(50mA)	31a	DO-7	BA 159	31a	BAY 20…21, BAY 46, BAY 88, BAW 52, ++
BA 130	Fch,Sgs,Tix	Si-Di	FM-/Vid-Dem, 25/30V, 75/115mA, Uf=0.69…1V(10mA)	31a	DO-7	(1N4148)	31a	BA 281, (BA128, BA222, 1N4148, 1N5194++)
BA 131	Sie	Si-Di	S, 600/600V, 0,3A, Uf<1,1V(0,2A)	31a	(7x3x3mm)	BA 159	31a	BA 199/550, BA 158…159, BY 204/8…10
BA 132	Sie	Si-Di	=BA 131: 800/800V	31a	(7x3x3mm)	BA 159	31a	BA 159, BY 204/8…10
BA 133(F)	Sie	Si-Di	=BA 131: 1000/1000V {F=DO-14	31a	(6x3x3mm)	BA 159	31a	BA 159, BY 204/10
BA 136(A)	Phi,Sie,Tho	C-Di	VHF Band-S, 50V, 0,9<2pF(30V), <1Ω(100MHz)	31a	DO-7			BA 243, BA 283, BA 483…484, ++
			BA 136A: 1,3<2pF(30V), <0,6Ω(100MHz)					
BA 137	Sie	Si-Di	S, 150V, 0,1A, Uf<1V(0,1A), <50ns	31a	DO-7	BA 159	31a	BA 196…198, BAV 20…21, BAY 80, 1N3070+
BA 138	Phi,Sie,Tho	C-Di	FM/VHF Tuning, 30V, 3,8…5,5pF(30V), 0,8Ω(300MHz)	31a	DO-7			BB 109, BB 143, MV 109, 1SV50, ++
BA 139	Phi,Sie	C-Di	UHF Tuning, 28V, 2…3/12,5pF(25/3V), 0,65Ω(330MHz)	31a	DO-7			BB 205A/B, BB 405A/B, BB 505B, 1SV148,++
BA 140	Sie	C-Di	FM/VHF Tuning, 28V, 2…3,2/12,5pF(25/3V), 1Ω(330M)	31a	DO-7			BB 109, BB 143, MV 109, 1SV50, ++
BA 141	Itt	C-Di	VHF/UHF Tuning, 28V, 2,2…3,2/12pF(25/3V), 0,5Ω	31a	DO-7			BB 205A/B, BB 405A/B, BB 505B, 1SV148,++
BA 142	Itt	C-Di	FM/VHF Tuning, 28V, 2,2…3,2/9…16pF(25/3V), 1Ω	31a	DO-7			BB 109, BB 143, MV 109, 1SV50, ++
BA 143 U	Itt	C-Di	UHF Band-S, 20V, 1,3<2pF(15V), 0,4Ω	31a				BA 244, BA 282, BA 284, BA 482, 1SS277
BA 143 V	Itt	C-Di	VHF Band-S, 20V, 1,3<2pF(15V), 0,7Ω	31a				BA 243, BA 283, BA 483…484, 1SS152,++
BA 144	Phi	Si-Di	50V, 50mA, Uf<3V(30mA)	31a	DO-7			-
BA 145	Phi,Mot	Si-Di	S, TV Clamping, 300/350V, 0,3/2A, Uf<1V(0,1A/75°)	31a	DO-14	BA 159	31a	BA 157…159, BA 245, BA 248, BY 206…207
BA 147/....	Aeg,Tix	Si-Di	Uni, 25…300V, 0,15/0,5A, Uf<1V(50mA)	31a	DO-7	BA 159	31a	BAY 17…21, BAY 86…88, BAY 44…46, ++
BA 148	Mot,Phi,Tho	Si-Di	S, TV Clamping, 300/350V, 0,3/3A, Uf<1,5V(2A)	31a	DO-14	BA 159	31a	BA 157…159, BA 245, BA 248, BY 206…207
BA 149/....	Aeg	C-Di	VHF/UHF Tuning, 50V, 5,3…8,3pF(2V), <1,5Ω(600MHz)	31a	DO-7			BB 205A/B, BB 405A/B, BB 505B, 1SV148,++
BA 150/....	Aeg,Phi,Tho	C-Di	FM Tuning, 25/28V, 44…66pF(2V)	31a	DO-7			BB 110, BB 203, 1SV68, 1SV84
BA 151	Aei,Tix	Si-Di	Stabi, 1V, Uf=0,6V/0,05mA	31a	SOD-17	1N4148	31a	BA 216, BA 314, BA 315, 1N4148, ++
BA 152(A,P,PR)	Tho	C-Di	VHF Band-S, 10/15V, 1,3<2pF(10V), 1Ω(50MHz)	31a	DO-7			BA 243, BA 283, BA 483…484, 1SS152,++
			BA 152A: 1,1<1,5pF(10V), 0,65Ω(50MHz) {P,PR=:		SOD-23			
BA 153	Tix	Si-Di	Dual, 40V, 25mA, Uf<0,9V(1mA)	7e	TO-98	2x 1N4148	31a	-
BA 154	Phi,Tix	Si-Di	Uni, 50/50V, 30/50mA, Uf<1,5V(30mA)	31a	SOD-17	1N4148	31a	BA 128, BA 222, BA 147/50, 1N4148, ++
BA 155	Fch,Phi,Tix	Si-Di	Uni, 150/150V, 0,1/0,15, Uf<1,5V(50mA)	31a	SOD-17	BA 159	31a	BA 147/150, BA 189…190, 1N5606…07, ++
BA 156	Phi,Tho	Si-St	Stabi, 30mA, Uf<0,7V(3mA)	31a	SOD-17	1N4148	31a	BA 216, BA 314, BA 315, 1N4148, ++
BA 157(GP)	Aeg,Itt,++	Si-Di	S, TV Clamping, 400V, 0,4/2A, Uf<1,5V(1A), <300ns	31a	DO-7	BA 159	31a	BY 204/4, BY 206, BY 406, BY 208/600, ++
			BA 157…159GP,DGP:		DO-41			
BA 158(GP)	Aeg,Itt,++	Si-Di	=BA 157: 600V	31a	DO-7	BA 159	31a	BY 204/8, BY 207, BY 407, BY 208/600, ++
BA 159(GP)	Aeg,Itt,++	Si-Di	=BA 157: 1000V	31a	DO-7	BA 159	31a	BY 204/10, BY 208/1000, BY 268, ++
BA 159 SGP	Gie	Si-Di	=BA 157: 1300V, <500ns	31a	DO-41	BY 228	31a	BY 231/1400, BY 268…269, RGP 15-14
BA 159 XGP	Gie	Si-Di	=BA 157: 1500V	31a	DO-41	BY 228	31a	BY 231/1500, BY 269, GP 15-16
BA 160	Itt	Si-Di	=BA 157: 1600V	31a	DO-7	BY 228	31a	BY 269, RGP 15-16
BA 161	Itt	C-Di	VHF/UHF Tuning, 28V, 2…2,7pF/12pF(25/3V), 0,5Ω	31a				BB 205A/B, BB 405A/B, BB 505B, 1SV148,++
BA 162	Itt	C-Di	FM/VHF Tuning, 28V, 2,2…3,2pF/9…16pF(25/3V), 1Ω	31a				BB 109, BB 143, MV 109, 1SV50
BA 163	Itt	C-Di	AM Tuning, 12V, 10pF/260pF(4…10V/0…1,5V), 1,5Ω	31a	DO-7			BB 112, BB 130, BB 509, 1SV134…135,++
BA 164	Sgs	Si-St	Stabi, 15/20V, 75mA, 0,25W, Uf=0,85<1V(10mA)	31a	DO-7	1N4148	31a	BA 216, BA 314, BA 315, 1N4148, ++
BA 165(A)	Tho	C-Di	VHF Band-S, 15/20V, 3pF(10V), 0,35Ω(50MHz)	31a	DO-7			BA 243, BA 283, BA 483, BA 484, 1SS152++
			BA 165A: 1,6<2pF(15V)					
BA 166	Gen,Tix	Si-Di	Uni, 20/20V, 50mA, Uf<1,4V(10mA)	31a	DO-35	1N4148	31a	BA 128, BA 222, BA 147/50, 1N4148, ++
BA 167	Gen,Tix	Si-Di	S, Uni, 25/25V, 50mA, Uf<1V(10mA), <200ns	31a	DO-35	1N4148	31a	BAX 88, BAX 94, BAY 93, 1N4148, ++
BA 168	Aei,Tix	Si-Di	S, 15V, 50mA, <4ns	31a	DO-35	1N4148	31a	BA 217, BA 317, BAY 71, 1N4148, ++
BA 169	Tho	Si-Di	20V, 75mA, Uf<0,78V(10mA)	31a	DO-35			-
BA 170	Itt,Gen,Tix	Si-Di	S, Uni, 20V, 0,15A, Uf<1V(80mA), 250ns	31a	DO-35	1N4148	31a	BAW 21, BAX 15…17, 1N4148, ++
BA 171	Itt	Si-Di	=BA 170: 30V, 100ns	31a	DO-35	1N4148	31a	BAW 21, BAX 15…17, 1N4148, ++
BA 172	Itt	Si-Di	=BA 170: 50V, 100ns	31a	DO-35	1N4148	31a	BAW 21, BAX 15…17, 1N4148, ++
BA 173	Aeg	Si-Di	S,TV Clamp, 300/350V, 0,3/3A, Uf<1V(100mA), <500ns	31a	DO-7	BA 159	31a	BA 157…159, BY 204/4, BY 206, BY 406,++
BA 174	Aeg	Si-Di	Min, S, 25/35V, 0,115/0,225A, Uf<1V(30mA), <35ns	36c	(TOM-23)	1N4148	31a	BAS 20, BAX 90, BAX 94, 1N4148, ++
BA 175	Aeg	Si-Di	Min, S, Uni, 50/75V, 0,25/0,6A, Uf<1V(0,1A),<300ns	36c	(TOM-23)	1N4148	31a	BAS 20, BAX 90, BAX 94, 1N4148, ++
BA 176	Aeg	Si-Di	Antennenschutz/Aerial protection, Uf<1,5V(0,4A)	31a	DO-7	(BA 159)	31a	(BA 157…159, BA 199/…, BY 208/…, ++)
BA 177	Aeg,Tho	C-Di	VHF Band-S, 50V, 2pF(2V), 0,45Ω(1MHz)	31a	DO-7			BA 243, BA 283, BA 483…BA 484, 1SS152++
BA 178	Aeg	C-Di	VHF Band-S, 35V, <1,3/<1,8pF(30/3V), <1,3Ω(200Mhz)	71a(4mm)	SOD-23			BA 243, BA 283, BA 483, BA 484, 1SS152++
BA 178 M05T	Rhm	Z-IC	Iso, +5V, 0,5A	17b	SOT-186	7805/IsoTO-220	17b	… 78M05…(TO-220 Iso)
BA 178 M06T	Rhm	Z-IC	Iso, +6V, 0,5A	17b	SOT-186	(7806/TO-220)[3]	17b	… 78M06…(TO-220 Iso)
BA 178 M07T	Rhm	Z-IC	Iso, +7V, 0,5A	17b	SOT-186			… 78M07…(TO-220 Iso)
BA 178 M08T	Rhm	Z-IC	Iso, +8V, 0,5A	17b	SOT-186	(7808/TO-220)[3]	17b	… 78M08…(TO-220 Iso)
BA 178 M09T	Rhm	Z-IC	Iso, +9V, 0,5A	17b	SOT-186	(7809/TO-220)[3]	17b	… 78M09…(TO-220 Iso)
BA 178 M10T	Rhm	Z-IC	Iso, +10V, 0,5A	17b	SOT-186	(7810/TO-220)[3]	17b	… 78M10…(TO-220 Iso)
BA 178 M12T	Rhm	Z-IC	Iso, +12V, 0,5A	17b	SOT-186	7812/IsoTO-220	17b	… 78M12…(TO-220 Iso)
BA 178 M15T	Rhm	Z-IC	Iso, +15V, 0,5A	17b	SOT-186	7815/IsoTO-220	17b	… 78M15…(TO-220 Iso)
BA 178 M18T	Rhm	Z-IC	Iso, +18V, 0,5A	17b	SOT-186	7818/IsoTO-220	17b	… 78M18…(TO-220 Iso)
BA 178 M20T	Rhm	Z-IC	Iso, +20V, 0,5A	17b	SOT-186	(7820/TO-220)[3]	17b	… 78M20…(TO-220 Iso)
BA 178 M24T	Rhm	Z-IC	Iso, +24V, 0,5A	17b	SOT-186	7824/IsoTO-220	17b	… 78M24…(TO-220 Iso)
BA 179	Tix	Si-Di	Dual, 50V, 25mA, <0,9V(1mA)	7e	TO-98	2x 1N4148	31a	-
BA 180(a,b,c)	Fch,Gen,Tix	Si-Di	Uni, 10V, 50/500mA, Uf<1V(4mA)	31a	DO-35	1N4148	31a	BA 128, BA 222, BA 147/25, 1N4148, ++
BA 181(A,B,C)	Fch,Gen,Tix	Si-Di	=BA 180: 20V	31a	DO-35	1N4148	31a	BA 128, BA 222, BA 147/25, 1N4148
BA 182	Aeg,Phi,Tho	C-Di	VHF Band-S, 35V, <1/<2,1pF(20/1V), 0,5Ω(200MHz)	71a(4mm)	SOD-23			BA 243, BA 283, BA 483, BA 484, 1SS152++
BA 184	Tix	Si-Di	S, Uni, 300/350V, 0,2/1A, Uf<1,1V(0,1A), 700ns	31a	DO-35	BA 159	31a	BA 157…159, BY 204/4, BY 206, BY 406,++
BA 185	Tix	Si-Di	=BA 184: 400/450V	31a	DO-35	BA 159	31a	BA 157…159, BY 204/4, BY 207, BY 407,++
BA 186	Tix	Si-Di	=BA 184: 450/500V	31a	DO-35	BA 159	31a	BA 159…159, BY 204/8, BY 207, BY 407,++
BA 187	Tix	Si-Di	Uni, 50V, 0,2A, Uf<1,2V(0,2A)	31a	DO-35	BA 159	31a	BAY 18, BAY 44, BAY 86, BA 157…159, ++
BA 188	Tix	Si-Di	=BA 187: 100V	31a	DO-35	BA 159	31a	BAY 19, BAY 45, BAY 87, BA 157…159, ++

Original	Fabric.	Constr.	Info	{Compl. Fig.		JAEGER	Fig.	International
BA 189	Tix	Si-Di	=BA 187: 150V	31a	DO-35	BA 159	31a	BAY 20, BAY 45, BAY 88, BA 157...159, ++
BA 190	Tix	Si-Di	=BA 187: 200V	31a	DO-35	BA 159	31a	BAY 20, BAY 46, BAY 88, BA 157...159
BA 191	Aeg	Si-Di	Schottky, S, UHF Mx, 20V, 0,05A, Uf<0,75V(10mA)	71a(4mm)	SOD-23	BAT 42	31a	BAT 42...43, BAT 47, BAT 85, 1SS293
BA 192	Tix	Si-Di	Uni, 50V, 0,4A, Uf<1V(0,4A)	31a	DO-7	BA 159	31a	BA 157...159, BA 199/250, BY 208/600, ++
BA 193	Tix	Si-Di	=BA 192: 100V	31a	DO-7	BA 159	31a	BA 157...159, BA 199/250, BY 208/600, ++
BA 194	Tix	Si-Di	=BA 192: 150V	31a	DO-7	BA 159	31a	BA 157...159, BA 199/250, BY 208/600, ++
BA 195	Tix	Si-Di	S, Uni, 200V, 0,15/0,5A, Uf<1V(0,1A), <50ns	31a	DO-35	(BA 159)	31a	BA 197, BAV 20, BAW 50, 1N3070, 1SS83
BA 196	Tix	Si-Di	S, Uni, 150V, 0,25A, Uf<0,75V(50mA), <50ns	31a	DO-35	(BA 159)	31a	BAV 20...21, BAW 50, 1SS83
BA 197	Tix	Si-Di	=BA 196: 200V	31a	DO-35	(BA 159)	31a	BAV 20...21, BAW 50, 1SS83
BA 198	Tix	Si-Di	=BA 196: 250V	31a	DO-35	(BA 159)	31a	BAV 21, 1SS83
BA 199/....	Tho,Tix	Si-Di	S, Uni, 250...550V, 0,4/1A, Uf<1V(0,1A), <1µs	31a	DO-7	BA 159	31a	BA 157...159, BY 204/..., BY 208/..., ++
BA 200	Itt	Si-Di	S, 35/45V, 0,15/0,2A, Uf<1,2V(0,1A), 4ns	31a	DO-35	1N4148	31a	BA 204, BAT 13, BAY 95, 1N3600, 1N4148
BA 201	Itt	Si-Di	=BA 200: 50/70V	31a	DO-35	1N4148	31a	BAW 46, BAW 62, BAY 61, BAX 95, 1N4148
BA 202	Itt	Si-Di	=BA 200: 75/100V	31a	DO-35	1N4148	31a	BAW 46, BAW 62, BAY 61, BAX 95, 1N4148
BA 203	Itt	Si-Di	=BA 200: 100/150V	31a	DO-35	(1N4148)	31a	BAV 14
BA 204	Aeg	Si-Di	S, 50/60V, 0,2/0,45A, Uf<1V(0,1A), <10ns	31a		1N4148	31a	BAT 13, BAW 62, BAY 95, 1N3600, 1N4148++
BA 205	Rhm	LIN-IC	Verstärker, Puffer/Amplifier, Buffer	16-DIP				-
BA 206	Tix	C-Di	AFC, 20V, 5,9pF(4V)	31a	DO-35			BA 121, BB 117, BB 417, 1SV89
BA 207	Tix	C-Di	AFC, 20V, 7...11pF(4V)	31a	DO-35			BA 121, BB 117, BB 417, 1SV89
BA 208	Tix	C-Di	AFC, 20V, 9...14pF(4V)	31a	DO-35			BA 121, BB 117, BB 417, 1SV89
BA 209	Tix	Si-Di	=1N4148	31a	DO-35	1N4148	31a	›1N4148
BA 210	Tix	Si-Di	=1N4149	31a	DO-35	1N4148	31a	›1N4149
BA 210	Rhm	LIN-IC	Modulator	16-DIP				-
BA 211	Tix	Si-Di	=1N4446	31a	DO-35	1N4148	31a	›1N4446
BA 212	Tix	Si-Di	=1N4447	31a	DO-35	1N4148	31a	›1N4447
BA 213	Tix	Si-Di	=1N4448	31a	DO-35	1N4148	31a	›1N4448
BA 214	Tix	Si-Di	=1N4449	31a	DO-35	1N4148	31a	›1N4449
BA 215	Tix	Si-Di	Uni, 60/60V, 0,2/0,25A, Uf<1,3V(0,2A)	31a	DO-35	1N4148	31a	BA 127, BA 188, BAY 73, 1N4148, ++
BA 215	Rhm	LIN-IC	FM IF	16-DIP				-
BA 216	Fch,Phi	Si-St	S, Stabi, 10V, 75/150mA, Uf<0,58...0,8V(3mA), <4ns	31a	SOD-17	1N4148	31a	BA 217...219, BA 315...317, 1N4148, ++
BA 217	Fch,Phi,Tix	Si-Di	S, 30/30V, 75/150mA, Uf<1,5V/50mA, <4ns	31a	SOD-17	1N4148	31a	BA 317...318, BAX 13, BAX 91, 1N4148, ++
BA 218	Fch,Phi,Tix	Si-Di	S, 50/50V, 75/150mA, Uf<1,5V(50mA), <4ns	31a	SOD-17	1N4148	31a	BA 318, BAX 13, BAX 91, BAY 38, 1N4148
BA 219	Fch,Phi,Tix	Si-Di	S, 100/100V, 0,1/0,3A, Uf<1,3V(50mA, <4ns	31a		1N4148	31a	BAW 47, BAX 96, 1N4148, 1SS115
BA 220	Phi,Tix	Si-St	S, Stabi, 10V, 0,2/0,4A, Uf<0,64...0,7V(5mA), <4ns	31a	DO-35	1N4148	31a	BA 221, BAY 74, 1N4154, 1N4148, ++
BA 221	Phi,Tix	Si-Di	S, Uni, 30V, 0,2/0,4A, Uf<1,05V(0,2A), <4ns	31a	DO-35	1N4148	31a	BAW 62, BAX 95, BAY 74, 1N4154, 1N4148
BA 222	Phi	Si-Di	Uni, 50/50V, 75/150mA, Uf<0,9V(10mA)	31a	DO-35	1N4148	31a	BA 128, BA 147/50, 1N4148, 1N5194, ++
BA 222	Rhm	LIN-IC	CR Timer, Ucc=4,5...16V, 0,2A, -20...+75°	7-SIP		BA 222*	7-SIP	-
BA 223	Phi	C-Di	AM Band-S, 20V, <3,5pF(6V), <1,5Ω(1MHz)	31a	DO-35			BA 423
BA 223-10...-70	Edl	Si-Di	Rr, 1000...7000V, 1A...0,15A, Uf<5...<10V(1A...0,15A)	31a	(6,3x3mmØ)			-
BA 223	Rhm	LIN-IC	CR Timer, Ucc=4,5...16V, 0,2A, -20...+75°	8-SIP				-
BA 224/....	Tho	Si-Di	S, Uni, 150...300V, 0,15/0,65A, Uf<1V(0,1A), <40ns	31a	DO-35			BA 196...198, BAV 20...21
BA 224	Rhm	LIN-IC	Timer	8-SIP				-
BA 224 F		LIN-IC	=BA 224: SMD	8-MDIP				-
BA 225	Fer	Si-Di	SMD, Dual, 25/50V, 50mA, Uf<1,1V(50mA), 6ns	35n(2mm)	SOT-323			-
BA 225	Rhm	LIN-IC	VC, CR Timer, 2x Multivibr., Ucc=4...16V, -20...+75°	8-DIP				-
BA 225 F	Rhm	LIN-IC	=BA 225: SMD	8-MDIP				-
BA 226	Fer	Si-Di	=BA 225[Fer]:	35f(2mm)	SOT-323			-
BA 226	Rhm	LIN-IC	VC, CR Timer, 2x Multivibr., Ucc=4...16V, -20...+75°	8-DIP				-
BA 226 F	Rhm	LIN-IC	=BA 226: SMD	8-MDIP				-
BA 227	Tix	Si-Di	Dual, 40V, 75mA, Uf<1V(10mA)	2	TO-5			-
BA 228	Tix	Si-Di	Dual, 40V, 75mA, Uf<1V(10mA)	2	TO-5			-
BA 235	Rhm	LIN-IC	=BA 225: Fig. ›	9-SIP				-
BA 236	Rhm	LIN-IC	=BA 226: Fig. ›	9-SIP				-
BA 243(A,S)	Itt,Phi,++	C-Di	VHF Band-S, 20/35V, 1,3<2pF(15V), 0,7<1Ω(200MHz) A: <1pF(20V), S: <1,5pF(5V)	31a	DO-35			BA 182, BA 283, BA 483, BA 484, 1SS152++
BA 244(A,S)	Itt,Phi,++	C-Di	VHF/UHF Band-S,20/35V, 1,3<2pF(15V), <0,5Ω(200MHz) A: <1pF(20V), S: <1,5pF(5V)	31a				BA 282, BA 284, BA 482, 1SS277
BA 245	Tix	Si-Di	S, TV, 350V, 0,4/2A, Uf<1,15V(0,1A), <300ns	31a	DO-7	BA 159	31a	BA 157...159, BY 204/4, BY 206, BY 406
BA 248	Tix	Si-Di	S, TV, 350V, 0,4/3A, Uf<1,75V(2A), <500ns	31a	DO-7	BA 159	31a	BA 157...159, BY 204/4, BY 206, BY 406
BA 280	Phi	Si-Di	Schottky, UHF Mx, 4V, 0,03A, <15Ω, F<8dB(900MHz)	71a(4mm)	SOD-23			BA 480...481, BAR 19, BAT 29, 1SS88,++
BA 281	Phi	Si-Di	Dem, 50V, 0,2/0,45A, Uf<1V(0,1A)	31a	DO-35	(1N4148)	31a	(BA 127, BA 187, BA 215, 1N4148, ++)
BA 282	Itt,Sie,++	C-Di	VHF/UHF Band-S, 35V, <1,2pF(3V), <0,7Ω(200MHz)	31a	DO-35			BA 244, BA 284, BA 482, 1SS277
BA 283	Itt,Sie,++	C-Di	VHF Band-S, 35V, <1pF(3V), <1,2Ω(200MHz)	31a	DO-35			BA 243, BA 483, BA 484, 1SS152
BA 284	Sie	C-Di	VHF/UHF Band-S, 35V, 0,8<1pF/1pF(20/1V), <0,6Ω	31a	DO-35			BA 244, BA 282, BA 482, 1SS277
BA 301	Rhm	LIN-IC	Uni, Audio Preamp., Ucc=12(6...20)V	7-SIP				-
BA 302	Rhm	LIN-IC	Audio Out, 1,8W(6V/8kΩ-Trafo)	7-SIP				-
BA 306	Rhm	LIN-IC	LF Treiber/driver	7-SIP				-
BA 307	Rhm	LIN-IC	LF Verstärker/Amplifier	7-SIP				-
BA 308	Rhm	LIN-IC	LF Inp In	7-SIP				-
BA 311	Rhm	LIN-IC	LF Inp	7-SIP				(BA 312)
BA 312	Rhm	LIN-IC	LF Inp	7-SIP				(BA 311)
BA 313	Rhm	LIN-IC	Recorder, Rec/Play Amp., ALC, Ucc=3...12V	9-SIP				(BA 314)
BA 314	Rhm	LIN-IC	=BA 313	9-SIP				(BA 313)
BA 314(A)	Phi,Tix	Si-St	Stabi, 0,1A, 0,68...0,76V(1mA), 0,87...0,96V(100mA) BA 314A: <0,78V(5mA)	31a	DO-35	(1N4148)	31a	BZX 62, BZX 84/C0V8, BZX 97/0V8
BA 315	Phi	Si-St	Stabi, S, 5V, 0,1A, 0,71...0,79V/10mA, <4ns	31a	DO-35	1N4148	31a	BA 316, BA 220, BAY 94, 1N4148, ++
BA 316	Phi	Si-Di	S, Uni, 10V, 0,1/0,225A, Uf<1,1V(0,1A), <4ns	31a	DO-35	1N4148	31a	BA 220, BA 221, BAY 94, 1N4148, ++
BA 317	Phi	Si-Di	=BA 316: 30V	31a	DO-35	1N4148	31a	BAY 71, BAY 74, 1N4154, 1N4148, ++
BA 318	Phi	Si-Di	=BA 316: 50V	31a	DO-35	1N4148	31a	BAX 80, BAY 38, BAY 95, 1N4148, ++
BA 318	Rhm	LIN-IC	Audio Inp, VU Meter Drv	7-SIP				-
BA 319	Phi	Si-Di	S, Uni, 75V, 0,25A, Uf<1,1V(0,1A), <50ns	31a	DO-35	1N4148	31a	BA 196, BAV 19, BAY 43, 1N4148, ++
BA 320	Phi	Si-Di	=BA 319: 100V	31a	DO-35	1N4148	31a	BA 196, BAV 19, BAW 50
BA 328	Rhm	LIN-IC	Dual Audio Inp, In, Ucc=8V	8-SIP		LA 3161	8-SIP	KA 2221, LA 3161, M5152L, TA 7375P
BA 328 F	Rhm	LIN-IC	=BA 328: SMD	8-MDIP				-
BA 329	Rhm	LIN-IC	Dual Audio Inp, In	9-SIP				-
BA 333	Rhm	LIN-IC	Recorder, Rec/Play Amp., ALC, Ucc=2,5...16V	9-SIP		LA 3210	9-SIP	KA 2220, LA 3210, TA 7137
BA 335	Rhm	LIN-IC	Recorder, Band-Suchlauf/Audio Level Sensor, Ucc=9V	9-SIP				-
BA 336	Rhm	LIN-IC	Recorder, Band-Suchlauf/Blank Sect. Detect.,Ucc=9V	9-SIP				BA 338
BA 337	Rhm	LIN-IC	Recorder, Auto-Reverse Controller,Ucc=13(4,2...16)V	9-SIP				-
BA 338	Rhm	LIN-IC	=BA 336: verbessert/improved	9-SIP				-
BA 338 L	Rhm	LIN-IC	=BA 336: verbessert/improved	9-SQP				-
BA 340	Rhm	LIN-IC	Audio Inp	8-SIP				-
BA 343	Rhm	LIN-IC	Recorder, Dual Audio Inp, ALC, Ucc=8V	16-DIP				-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BA 379	Phi,Sie,Tho	PIN-Di	VHF/UHF, 30V, 20mA, Uf<1V(20mA), 0,3pF(0V/900MHz)		(31a)	SOD-52			BA 382, MPN 3401, MPN 3402
BA 382	Mot	PIN-Di	VHF/UHF, VHF Band-S, 40V, 0,75pF(1V), 0,34Ω(10mA)		71a(4mm)	≈SOD-23			MPN 3401, MPN 3402
BA 389	Sie	PIN-Di	1MHz…1GHz, 30V, 50mA, 0,55pF(10V), 5Ω(10V/100MHz)		31a	DO-35			BA 479
BA 401	Rhm	LIN-IC	TV, Sound IF, FM IF, Ucc=12V		5-SIP		BA 401*	5-SIP	-
BA 401 F	Rhm	LIN-IC	=BA 401: SMD		8-MDIP				-
BA 402	Rhm	LIN-IC	TV, Sound IF, FM IF		7-SIP		BA 402*	7-SIP	-
BA 403	Rhm	LIN-IC	FM IF, Demodulator, Ucc=8…15V		7-SIP		TA 7130 P	7-SIP	KA 2245, LA 1150, TA 7130P, µPC 1028H
BA 404	Rhm	LIN-IC	FM IF		9-SIP				KA 2244, TA 7303
BA 423	Phi	C-Di	AM-Band-S, 20V, 50mA, <2,5pF(3V), <1,2Ω(10mA)		31a	DO-34			BA 223
BA 423 L		C-Di	=BA 423		72a(3,4mm)	SOD-80			-
BA 479(A,G,S)	Aeg	PIN-Di	10…1000MHz, 30V, 50mA, <0,5pF(0V), <50Ω(1,5mA)		71a(4mm)	SOD-23			BA 389
BA 480	Phi	Si-Di	Schottky, UHF Mx, 4/5V, 30mA, Uf<0,28V(1mA)		31a	DO-34			BAR 19, BAT 29, BAT 45, 1S1925
BA 481	Phi	Si-Di	Schottky, UHF Mx, 4/5V, 30mA, <0,45V(1mA)		31a	DO-34			BAR 19, BAT 29, BAT 45, 1S1925
BA 482	Phi,Tho	C-Di	VHF Band-S, 35V, 0,1A, <1,2pF(3V), <0,7Ω(3mA)		31a	DO-34			BA 243, BA 283, BA 483…484, 1SS152,++
BA 483	Phi,Tho	C-Di	VHF Band-S, 35V, 0,1A, <1pF(3V), <1,2Ω(3mA)		31a	DO-34			BA 243, BA 283, BA 483…484, 1SS152,++
BA 484	Phi,Tho	C-Di	VHF Band-S, 35V, 0,1A, <1,6pF(3V), <1,2Ω(3mA)		31a	DO-34			BA 243, BA 283, BA 483…484, 1SS152,++
BA 501	Rhm	LIN-IC	Audio Out, 18V, 1,5A, 4W(13V/4Ω)		8-SIL				-
BA 505	Rhm	LIN-IC	Audio Drv		14-DIP+g				-
BA 505 G	Sie	Si-Di	CATV, VHF Tuning						-
BA 511(A)	Rhm	LIN-IC	Audio Out, 4,5W(13V/4Ω)		10-SIL		BA 532	10-SIL	BA 532
BA 514	Rhm	LIN-IC	Audio Inp+Out, 2W(9V/4Ω)		8-SIL		BA 514*	8-SIL	-
BA 515	Rhm	LIN-IC	Audio Out, 15V, 0,23W(3V/4Ω)		12-SQP				-
BA 516	Rhm	LIN-IC	Audio Out, 0,35W(9V/8Ω)		9-SIP				BA 526, BA 527
BA 518	Rhm	LIN-IC	Audio Out, 1,5W(12V/8Ω)		8-SIL				BA 547
BA 521(S)	Rhm	LIN-IC	Audio Out, 5,8W(13V/4Ω), S=verbessert/improved		10-SIL		BA 532	10-SIL	BA 532
BA 524	Rhm	LIN-IC	Audio Out, 3,8W(12V/4Ω)		10-SIL				-
BA 526	Rhm	LIN-IC	Audio Out, 0,43W(6V/8Ω)		9-SIP				BA 527
BA 527	Rhm	LIN-IC	Audio Out, 0,8W(6V/4Ω)		9-SIP				KIA 6278S
BA 532	Rhm	LIN-IC	Audio Out, 5,8W(13V/4Ω)		10-SIL		BA 532	10-SIL	-
BA 534	Rhm	LIN-IC	Audio Out, 2,3W(9V/4Ω)		10-SIL				BA 524
BA 535	Rhm	LIN-IC	2x Audio Out, 20V, 2x4,8W(12V/4Ω)		12-SILP				(BA 536)
BA 536	Rhm	LIN-IC	2x Audio Out, 2x4,5W(12V/4Ω)		12-SILP				BA 5402(A)
BA 546	Rhm	LIN-IC	Audio Out, 12V, 0,33W(6V/8Ω)		9-SIP				BA 527
BA 547	Rhm	LIN-IC	Audio Out, 1,5W(12V/8Ω)		8-SIL				BA 518
BA 555	Rhm	LIN-IC	=NE 555		8-DIP		NE 555 N	8-DIP	›NE 555
BA 567	Rhm	LIN-IC	=LM 567CN		8-DIP		›LM 567		›LM 567CN
BA 579 A	Tho	PIN-Di	SMD, Dual, VHF/UHF, 30V, 20mA, 0,35pF(1V), 4,5Ω		35n	SOT-23			-
BA 579 C(K)		PIN-Di	=BA 579A:		35f	SOT-23			-
BA 579 S		PIN-Di	=BA 579A:		35t	SOT-23			-
BA 582	Phi,Sie	C-Di	SMD, TV, VC, VHF Band-S, 35V, <1,4pF(1V), <0,7Ω		71a(2,7mm)	SOD-123			1SS241
BA 585	Sie	PIN-Di	HF Att, 50V, 50mA, 1…2000MHz, <0,4pF(0V)		71a(2,7mm)	SOD-123			-
BA 586	Sie	PIN-Di	HF Att, 50V, 50mA, >1MHz, <0,35pF(0V)		71a(2,7mm)	SOD-123			-
BA 592	Sie	C-Di	=BA 582:		71a(1,7mm)	SOD-323			1SS314, 1SS356
BA 595	Sie	PIN-Di	=BA 585:		71a(1,7mm)	SOD-323			-
BA 596	Sie	PIN-Di	=BA 586:		71a(1,7mm)	SOD-323			-
BA 604	Aeg	Si-Di	SMD, Uni, S, 50V, 0,2/0,45, Uf<1,1V(50mA), <20ns		72a(3,4mm)	SOD-80			-
BA 612	Rhm	LIN-IC	5x PNP Darl.-Transistor, 26V, 0,4A, hFE>2000		14-DIP				-
BA 614(A)	Rhm	LIN-IC	6x PNP Darl.-Trans., 20V, 0,1A, Usat<2,2V(75mA)		14-DIP				-
BA 618	Rhm	LIN-IC	7x LED/LCD Drv, Ucc=10V, 0,1A		16-DIP				-
BA 621	Rhm	LIN-IC	Analog-Schalter/Switch		5-SIP				-
BA 631	Rhm	LIN-IC	FM Intercom		14-DIP				-
BA 634	Rhm	LIN-IC	T-Flipflop, Reset, Uee=-16V		5-SIP				-
BA 634 F		LIN-IC	=BA 634: SMD		8-MDIP				-
BA 653	Rhm	LIN-IC	Berührungsschalter/Touch Sensor		16-DIP				-
BA 656	Rhm	LIN-IC	LED Linear-Meter, 5 LED		9-SIP				(KA 2286, LB 1413)
BA 658	Rhm	LIN-IC	12P. VU-Meter Drv(FLT Display)		16-DIP				-
BA 664	Rhm	LIN-IC	6x Uni Drv, Ucc=20V, 0,1A, Usat<2,2V(75mA)		14-DIP				-
BA 668(A)	Rhm	LIN-IC	12P. VU-Meter Drv(FLT Display), Peak Hold, Ucc=16V		18-DIP				-
BA 679(S)	Aeg	PIN-Di	=BA 479(A,G,S): SMD		72a(3,4mm)	SOD-80			BA 979
BA 681 A	Rhm	LIN-IC	LED Linear-Meter Drv, 12 LED, Ucc=12V		18-DIP				-
BA 682	Itt,Sie,++	C-Di	=BA 282: SMD		72a(3,4mm)	SOD-80			BA 982
BA 682 A	Rhm	LIN-IC	LED VU-Meter Drv, 12 LED, Ucc=12V		18-DIP				-
BA 682 AF	Rhm	LIN-IC	=BA 682A: SMD		18-MDIP				-
BA 683	Itt,Sie,++	C-Di	=BA 283: SMD		72a(3,4mm)	SOD-80			BA 983
BA 683 A	Rhm	LIN-IC	LED Level-Meter Drv, 12 LED, Ucc=12V		18-DIP				-
BA 684 A	Rhm	LIN-IC	LED Linear-Meter Drv, 8 LED, Ucc=12(6,5…14)V		16-DIP				-
BA 685	Rhm	LIN-IC	LED Linear Meter Drv, 5 LED, Ucc=13(6,5…14)V		16-DIP				-
BA 689	Rhm	LIN-IC	LED Linear-Meter Drv, 12 LED, Ucc=12V		18-DIP				-
BA 695	Rhm	LIN-IC	AM/FM LED/LCD Tuning Indicator, 3 LED, Ucc=12V		9-SIP				-
BA 704	Rhm	Z-IC	2,65V, 1,5mA, ±0,3mV/°C		7b	TO-92			-
BA 707	Rhm	Z-IC	3,3V, 1,8mA, ±0,3mV/°C		7b	TO-92			-
BA 714	Rhm	Z-IC	3,3V, 50….250µA		9d	(FTR)			-
BA 715	Rhm	OP-IC	Dual, Serie 158		9-SIP				-
BA 718	Rhm	OP-IC	Dual		9-SIP				-
BA 728	Rhm	OP-IC	Dual, lo-power, ±9V, -20…+75°		8-DIP				-
BA 728 F		OP-IC	=BA 728: SMD		8-MDIP				-
BA 728 N		OP-IC	=BA 728: Fig. ›		8-SIP				-
BA 735 F	Rhm	OP-IC	Dual		8-MDIP				-
BA 779(S)	Aeg	PIN-Di	=BA 479G(S): SMD		35p	SOT-23			-
BA 779-2		PIN-Di	=BA 479(S): SMD, Dual		35t	SOT-23			-
BA 802	Rhm	LIN-IC	PLL Motor Controller		5-SIP				-
BA 806	Rhm	LIN-IC	PLL Motor Controller		5-SIP				-
BA 820	Rhm	LIN-IC	8-Bit Serial In Parallel Out Driver		16-DIP				-
BA 823	Rhm	LIN-IC	8-Bit Serial In Parallel Out Driver, Ucc=5V		16-DIP				-
BA 823 F		LIN-IC	=BA 823: SMD		16-MDIP				-
BA 829	Rhm	LIN-IC	8-Bit Serial In Parallel Out Driver, Ucc=5V		18-DIP				-
BA 841	Rhm	LIN-IC	VC, Servo						-
BA 842	Rhm	LIN-IC	Recordersteuerung/Tape Deck Controller		40-DIP				-
BA 843	Rhm	LIN-IC	Recorder, Tastenstrg./Key Controller,Ucc=4,5…5,5V		16-DIP				-
BA 843 F		LIN-IC	=BA 843: SMD		16-MDIP				-
BA 845	Rhm	LIN-IC	Recorderspeicher/Memory		24-DIP				-
BA 847	Rhm	LIN-IC	VC-Servo, Bildschnitt/Special Playback		22-DIP				-
BA 852	Rhm	LIN-IC	VC, Servo Ctrl., FG System		16-DIP				-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BA 855(A)	Rhm	LIN-IC	VC, Servo, Special Playback(Fine Slow)		20-DIP				-
BA 855 F,AF	Rhm	LIN-IC	=BA 855: SMD		20-MDIP				-
BA 856	Rhm	LIN-IC	VC, Servo, Special Playback(Fine Still)		16-DIP				-
BA 857	Rhm	LIN-IC	VC, Servo, Special Playback(Fine Slow)		18-DIP				-
BA 857 F		LIN-IC	=BA 857: SMD		18-MDIP				-
BA 860	Rhm	LIN-IC	VC, Servo, Motor Speed & Phase Control		16-DIP				-
BA 862	Rhm	LIN-IC	VC, Servo, Special Playback(Fine Slow)		18-DIP				-
BA 866 F	Rhm	LIN-IC	VC, Servo, Special Playback(Fine Slow)		18-MDIP				-
BA 867	Rhm	LIN-IC	VC, Servo, Special Playback(Fine Slow)		18-DIP				-
BA 873	Rhm	LIN-IC	VC, Reel Sensor, Ucc=4,2…12V		16-DIP				-
BA 875	Rhm	LIN-IC	VC, Servo, Special Playback(Fine Slow)		28-DIP				-
BA 875 F	Rhm	LIN-IC	=BA 875: SMD		28-MDIP				-
BA 877 LS	Rhm	LIN-IC	VC, Servo, Special Playback(Fine Slow)		24-SQP				-
BA 885	Sie	PIN-Di	=BA 585:		35p	SOT-23			-
BA 886	Sie	PIN-Di	=BA 586:		35p	SOT-23			-
BA 979(S)	Aeg	PIN-Di	=BA 479G(S): SMD		72a(3,5mm)	DO-213			-
BA 982	Aeg	C-Di	=BA 282: SMD		72a(3,5mm)	DO-213			BA 682
BA 983	Aeg	C-Di	=BA 283: SMD		72a(3,5mm)	DO-213			BA 683
BA 1310	Rhm	LIN-IC	Stereo-Decoder		14-DIP		BA 1310*	14-DIP	AN 115
BA 1310 F		LIN-IC	=BA 1310: SMD		14-MDIP				-
BA 1320	Rhm	LIN-IC	FM Multiplex Stereo-Decoder, Ucc=12(5,4…14)V		16-DIP		BA 1320*	16-DIP	AN 363, µPC 1320
BA 1320 F		LIN-IC	=BA 1320: SMD		16-MDIP				-
BA 1330	Rhm	LIN-IC	=BA 1320: Ucc=3,6….6V		16-DIP		BA 1330*	16-DIP	AN7410, HA11227, KA2261, LA3361, TA7604
BA 1330 F		LIN-IC	=BA 1330: SMD		16-MDIP				-
BA 1332	Rhm	LIN-IC	FM Multiplex Stereo-Decoder, Ucc=6>3V		16-DIP		BA1320, BA1330	16-DIP	BA 1320, BA 1330
BA 1332 F		LIN-IC	=BA 1332: SMD		16-MDIP				-
BA 1332 L		LIN-IC	=BA 1332: Fig. ›		16-SQP				-
BA 1335	Rhm	LIN-IC	FM MPX Stereo-Decoder, Ucc=5(3,3…9)V		16-DIP				-
BA 1335 F		LIN-IC	=BA 1335: SMD		16-MDIP				-
BA 1350	Rhm	LIN-IC	FM MPX Stereo-Decoder, Noise Ctrl., Ucc=9(6…12)V		16-SQP				-
BA 1350 F		LIN-IC	=BA 1350: SMD		16-MDIP				-
BA 1351	Rhm	LIN-IC	=BA 1350: Fig. ›		16-DIP				-
BA 1355	Rhm	LIN-IC	FM MPX Stereo-Decoder, Noise Ctrl., Ucc=9(5….12)V		16-DIP				-
BA 1355 F		LIN-IC	=BA 1355: SMD		16-MDIP				-
BA 1356	Rhm	LIN-IC	FM MPX Stereo-Decoder, Noise Ctrl., Ucc=9(5…12)V		16-SQP				-
BA 1356 F		LIN-IC	=BA 1356: SMD		16-MDIP				-
BA 1360	Rhm	LIN-IC	FM MPX Stereo-Decoder, Ucc=1,8….3V		16-SQP				-
BA 1360 F		LIN-IC	=BA 1360: SMD		16-MDIP				-
BA 1362 F	Rhm	LIN-IC	SMD, FM MPX Stereo-Decoder, Ucc=1,5(1…2,5)V		16-MDIP				-
BA 1362 FS	Rhm	LIN-IC	=BA 1362F:		16-SMDIP				-
BA 1402	Rhm	LIN-IC	FM Stereo Radio, Ucc=1,5V, Icc=11mA		22-DIP				-
BA 1402 F		LIN-IC	=BA 1402: SMD		22-MDIP				-
BA 1404	Rhm	LIN-IC	FM Stereo-Sender/Transmitter, Ucc=1,25(1…2)V		18-DIP				-
BA 1404 F		LIN-IC	=BA 1404: SMD		18-MDIP				-
BA 1407 AF	Rhm	LIN-IC	=BA 1407AL: SMD		20-MDIP				-
BA 1407 AL	Rhm	LIN-IC	TV, Multiplex Dem., Japan-Standard, Ucc=4…11V		18-SQP				-
BA 1440	Rhm	LIN-IC	AM Tuner, FM IF, FM Stereo-Decoder, Ucc=3,5…7V		18-DIP				-
BA 1441	Rhm	LIN-IC	AM Tuner, FM IF, FM Stereo-Decoder, Ucc=3,5…7V		18-DIP				-
BA 1442 A	Rhm	LIN-IC	AM Radio, FM IF Stereo System, Ucc=3,8…8V		20-DIP				-
BA 1443 A	Rhm	LIN-IC	AM Radio, FM IF Stereo System, Ucc=3,8…8V		20-DIP				-
BA 1602 L	Rhm	LIN-IC	FM Intercom		18-SQP				-
BA 1604	Rhm	LIN-IC	Telecom, PLL Tone Decoder		8-DIP				›LM 567CN
BA 1604 F		LIN-IC	=BA 1604: SMD		8-MDIP				
BA 1610	Rhm	LIN-IC	Telecom, FSK Linear Modem		20-DIP				-
BA 1701	Rhm	LIN-IC	VSC(Voice Compression System)Processor, Ucc=6V		16-DIP				-
BA 2266	Rhm	LIN-IC	Radio-Servo		18-DIP				-
BA 3112	Rhm	LIN-IC	2x Audio Inp, Uni, Ucc=6…16V, Gv=10dB		8-SIP				BA 3113, BA 3114, BA 3116
BA 3113	Rhm	LIN-IC	=BA 3112: Gv=15dB		8-SIP				BA 3114, BA 3116
BA 3114	Rhm	LIN-IC	=BA 3112: Gp=20dB		8-SIP				BA 3116
BA 3116	Rhm	LIN-IC	=BA 3112: Gv=30dB		8-SIP				-
BA 3118 L	Rhm	LIN-IC	2x Audio Verst./Amp, Ucc=4…16V, Gp=6…20dB		18-SQP				-
BA 3120	Rhm	LIN-IC	Massefrei Verst./Ground Insulated Amp. f.Car Radio		8-DIP				-
BA 3120 F		LIN-IC	=BA 3120: SMD		8-MDIP				-
BA 3120 N		LIN-IC	=BA 3120: Fig. ›		8-SIP				-
BA 3121	Rhm	LIN-IC	Massefrei Verst./Ground Insulated Amp. f.Car Radio		8-DIP				-
BA 3121 F		LIN-IC	=BA 3121: SMD		8-MDIP				-
BA 3121 N		LIN-IC	=BA 3121: Fig. ›		8-SIP				-
BA 3126 F		LIN-IC	=BA 3126: SMD		14-MDIP				-
BA 3126 N	Rhm	LIN-IC	Recorder, 2x Kopfumsch./Head Switch, Ucc=4,5…15V		9-SIP				-
BA 3128 F		OP-IC	=BA 3128N: SMD		8-MDIP				-
BA 3128 N	Rhm	OP-IC	VC, LF, Audio Switched, ±18V, 6,5MHz, -20…+75°		8-SIP				-
BA 3129	Rhm	OP-IC	Dual, Audio Switched, ±18V, 6,5MHz, -20…+75°		14-DIP				-
BA 3129 F		OP-IC	=BA 3129: SMD		14-MDIP				-
BA 3302	Rhm	LIN-IC	2x LF Inp		8-SIP				-
BA 3304	Rhm	LIN-IC	Dual Audio Vorverst./Preamp., Ucc=3V		16-SQP				-
BA 3304 F		LIN-IC	=BA 3304: SMD		16-MDIP				-
BA 3306	Rhm	LIN-IC	Dual Audio Vorverst./Preamp., ALC, Ucc=4,5…14V		9-SIP				-
BA 3308	Rhm	LIN-IC	Dual Audio Vorverst./Preamp., ALC, Ucc=4,5…14V		9-SIP				KA 22241
BA 3308 F		LIN-IC	=BA 3308: SMD		14-MDIP				-
BA 3310 N	Rhm	LIN-IC	Dual Audio Vorverst./Preamp., ALC, Ucc=4…12V		10-SIP				KA 22241
BA 3312 N	Rhm	LIN-IC	Dual Audio Vorverst./Preamp., ALC, Ucc=4…12V		10-SIP				KA 22242
BA 3402	Rhm	LIN-IC	Recorder, Dual Autoreverse Preamp., Ucc=8V		16-SQP				-
BA 3402 F		LIN-IC	=BA 3402: SMD		16-MDIP				-
BA 3404 F	Rhm	LIN-IC	SMD, Recorder, Dual Autoreverse Preamp., Ucc=3V		16-MDIP				-
BA 3404 FS		LIN-IC	=BA 3404F: 4,4 x 6,6mm		16-SMDIP				-
BA 3404 L		LIN-IC	=BA 3404F: Fig. ›		16-SQP				-
BA 3406 AF		LIN-IC	=BA 3406AL: SMD		16-MDIP				-
BA 3406 AL	Rhm	LIN-IC	Recorder, Dual Preamp., Muting, Ucc=6…14V		16-SQP				-
BA 3408	Rhm	LIN-IC	Recorder, Dual Autoreverse Preamp., Ucc=8(6…14)V		16-DIP				-
BA 3408 F		LIN-IC	=BA 3408: SMD		16-MDIP				-
BA 3410 AF	Rhm	LIN-IC	SMD, Recorder, Rec/Play Amp., Ucc=3V		16-MDIP				-
BA 3412 K	Rhm	LIN-IC	Autoreverse Recorder, 2x Rec/Play Amp., Ucc=3V		32-MP				-
BA 3413 F	Rhm	LIN-IC	SMD, Recorder, Dual Autoreverse Preamp., Ucc=1,5V		16-MDIP				-

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
BA 3413 FS		LIN-IC	=BA 3413: 4,4 x 6,6mm		16-SMDIP			-
BA 3414 L	Rhm	LIN-IC	Transceiver Mikrofon-Verst./Microphone Amp.		16-SQP			-
BA 3416 BL	Rhm	LIN-IC	Recorder, Dual Playback Preamp., Ucc=3,5...12V		18-SQP			-
BA 3420 AL	Rhm	LIN-IC	Recorder, Dual Rec/Play Amp., Ucc=5...16V		18-SQP			-
BA 3422 S	Rhm	LIN-IC	Dual Recorder, Rec/Play System Preamp., Ucc=5...9V		32-SDIP			-
BA 3423 S	Rhm	LIN-IC	Recorder Ctrl., Dual Rec/Play Amp., Ucc=4,5...7V		32-SDIP			-
BA 3424 F	Rhm	LIN-IC	=BA 3424S: SMD		20-MDIP			-
BA 3424 FS	Rhm	LIN-IC	=BA 3424S: SMD, 8,7 x 5,4mm		20-SMDIP			-
BA 3424 S	Rhm	LIN-IC	Recorder, Dual Autoreverse Preamp., Ucc=9(7...18)V		22-SDIP			-
BA 3430 F	Rhm	LIN-IC	=BA 3430S: SMD		24-MDIP			-
BA 3430 FS		LIN-IC	=BA 3430S: SMD		24-SMDIP			-
BA 3430 S		LIN-IC	Recorder, Dual Vorverst./Preamp., AMS, Ucc=7...18V		24-SDIP			-
BA 3502 F	Rhm	LIN-IC	SMD, 2x Recorder Inp,Out, Ucc=3V		24-MDIP			KA 22131
BA 3503 F	Rhm	LIN-IC	SMD, 2x Recorder Inp,Out, Ucc=3V		24-MDIP			-
BA 3504 F	Rhm	LIN-IC	SMD, 2x Recorder Inp,Out, Ucc=3V		24-MDIP			-
BA 3505 F	Rhm	LIN-IC	SMD, 2x Recorder Inp,Out, Ucc=3V		24-MDIP			-
BA 3506 A	Rhm	LIN-IC	Recorder, Dual Audio Inp, Out, Ucc=3(1,8...3,8)V		16-DIP			-
BA 3506 AF		LIN-IC	=BA 3506A: SMD		18-MDIP			-
BA 3513 AF	Rhm	LIN-IC	SMD, Recorder, Dual LF Inp, Out, Ucc=3(1,8...3,6)V		24-MDIP			-
BA 3513 AFS		LIN-IC	=BA 3513AF: 10 x 5,4mm		24-SMDIP			-
BA 3514 AF	Rhm	LIN-IC	SMD, Recorder, Dual LF Inp, Out, Ucc=3(1,8...3,6)V		24-MDIP			-
BA 3516	Rhm	LIN-IC	Recorder, Dual Audio Inp, Out, Ucc=3(1,8...3,6)V		16-DIP			-
BA 3516 F		LIN-IC	=BA 3516: SMD		18-MDIP			-
BA 3518	Rhm	LIN-IC	Recorder, Audio Inp, Out, Ucc=3(1,8...4)V		16-DIP			-
BA 3518 F		LIN-IC	=BA 3518: SMD		16-MDIP			-
BA 3519 F	Rhm	LIN-IC	SMD, Recorder, Dual, LF Inp, Out, Ucc=3(1,8...4)V		22-MDIP			-
BA 3519 FS		LIN-IC	=BA 3519: SMD, 10 x 5,4mm		24-SMDIP			-
BA 3520	Rhm	LIN-IC	Recorder, Dual, Audio Inp, Out, Ucc=3(1,8...4)V		18-DIP			-
BA 3520 F		LIN-IC	=BA 3520: SMD		18-MDIP			-
BA 3521	Rhm	LIN-IC	Recorder, Dual, Audio Inp, Out, Ucc=3(1,8...4)V		18-DIP			-
BA 3528 FP	Rhm	LIN-IC	SMD, Recorder, Dual LF Proc., Motor Ctrl. Ucc=3V		28-MDIP+b			-
BA 3529 FP	Rhm	LIN-IC	SMD, Recorder, Dual LF Proc., Motor Ctrl. Ucc=3V		28-SMDIP+b			-
BA 3558 K	Rhm	LIN-IC	SMD, CD, Endverst./Post Amp., Low-pass Filter		32-MP			-
BA 3570 F	Rhm	LIN-IC	SMD, Kopfh.-Verst./Headphone Drv, Ucc=2...7.2V		22-MDIP			-
BA 3570 FS		LIN-IC	=BA 3570F: SMD		24-SMDIP			-
BA 3702	Rhm	LIN-IC	Recorder, Suchlaufspeicher/5-Item Select, Ucc=9V		16-DIP			-
BA 3704	Rhm	LIN-IC	Recorder, Suchlaufspeicher/3-Item Select		16-DIP			-
BA 3704 F		LIN-IC	=BA 3704: SMD		16-MDIP			-
BA 3706	Rhm	LIN-IC	Recorder, Suchlaufspeicher/Memory		16-DIP			-
BA 3707	Rhm	LIN-IC	Recorder, Band-Suchlauf/Blank Sect. Detect.,Ucc=6V		9-SIP			-
BA 3708 F		LIN-IC	SMD, =BA 3707, Ucc=3(1,8...5)V		8-MDIP			-
BA 3710	Rhm	LIN-IC	Recorder, Band-Suchlauf/Music Finder		16-DIP			-
BA 3711	Rhm	LIN-IC	Recorder, Suchlaufspeicher/3-Item Select		16-DIP			-
BA 3712	Rhm	LIN-IC	Recorder, Auto-Reverse Controller, Ucc=13(7...16)V		9-SIP			-
BA 3714 F	Rhm	LIN-IC	Recorder, 1,5V Signal Sensor, Ucc=1,25(0,8...4,5)V		8-MDIP			-
BA 3810 F	Rhm	LIN-IC	SMD, Recorder Controller, Ucc=3V		22-MDIP			-
BA 3812 F		LIN-IC	=BA 3812L: SMD		20-MDIP			-
BA 3812 L	Rhm	LIN-IC	Graphic Equalizer, 5 Point, Ucc=8(3,5...16)V		18-SQP			KA 22235
BA 3814 L	Rhm	LIN-IC	Communic. System Power on/off Controller		16-SQP			-
BA 3818 F	Rhm	LIN-IC	SMD, Recorder, 5-Point Comp. Array, Ucc=1.6...3.6V		8-MDIP			-
BA 3819 F	Rhm	LIN-IC	SMD, Recorder, 5-Point Comparator Array, Ucc=2...5V		8-MDIP			-
BA 3822 FS		LIN-IC	=BA 3822LS: SMD		24-SMDIP			-
BA 3822 LS	Rhm	LIN-IC	Graphic Equalizer, Stereo, 5 Points, Ucc=3,5...14V		24-SQP			KA 22234
BA 3823 LS	Rhm	LIN-IC	Graphic Equalizer, Stereo, 5 Points, Ucc=3,5...14V		24-SQP			-
BA 3824 LS	Rhm	LIN-IC	Graphic Equalizer, Stereo, 5 Points, Ucc=3,5...14V		24-SQP			-
BA 3826 S	Rhm	LIN-IC	Band-pass Filter f. Spectrum Analyzers, 7 Channel		18-SDIP			-
BA 3828 F	Rhm	LIN-IC	SMD, Recorder, Preset+Comparator Array		22-MDIP			-
BA 3830 F		LIN-IC	=BA 3830S: SMD		18-MDIP			-
BA 3830 S	Rhm	LIN-IC	Bandpass-Filter f. Spectroanalyzer, Ucc=5(4,5...8V)		18-SDIP			-
BA 3832 F	Rhm	LIN-IC	SMD, Bandpass-Filter f. Spectroanalyzer, Ucc=5V		18-MDIP			-
BA 3853 AFS	Rhm	LIN-IC	Dual Potentiometer (Sound Ctrl.) f. Car Stereo		24-SMDIP			-
BA 3870	Rhm	LIN-IC	Recorder, Bass Boost System, Ucc=3...7V		20-DIP			-
BA 3900	Rhm	LIN-IC	Car Audio, Referenz-Spg.-/Ref.Vltg. Generator		12-SILP			-
BA 3902	Rhm	LIN-IC	Car Audio, Referenz-Spg.-/Ref.Vltg. Generator		12-SILP			-
BA 3904 A	Rhm	LIN-IC	Car Audio, Referenz-Spg.-/Ref.Vltg. Generator		12-SILP			-
BA 3906	Rhm	LIN-IC	Car Audio, Referenz-Spg.-/Ref.Vltg. Generator		12-SILP			-
BA 3908 B	Rhm	LIN-IC	Car Stereo, Stromversorgung/Power Supply		12-SILP			-
BA 3910 B	Rhm	LIN-IC	Car Stereo, Referenz-Spg.-/Ref.Vltg. Generator		12-SILP			-
BA 3912	Rhm	LIN-IC	Car Stereo, Stromversorgung/Power Supply		12-SILP			-
BA 3913	Rhm	LIN-IC	Car Stereo, Stromversorgung/Power Supply		12-SILP			-
BA 3920	Rhm	LIN-IC	CD Radio Cass., Referenz-Spg.-/Ref.Vltg. Generator		12-SILP			-
BA 3922	Rhm	LIN-IC	CD Radio Cass., Referenz-Spg.-/Ref.Vltg. Generator		12-SILP			-
BA 3924	Rhm	LIN-IC	CD Radio Cass., Referenz-Spg.-/Ref.Vltg. Generator		12-SILP			-
BA 3926	Rhm	LIN-IC	CD Radio Cass., Referenz-Spg.-/Ref.Vltg. Generator		12-SILP			-
BA 3928	Rhm	LIN-IC	CD Radio Cass., Referenz-Spg.-/Ref.Vltg. Generator		12-SILP			-
BA 3930	Rhm	LIN-IC	CD Radio Cass., Stromversorgung/Power Supply		12-SILP			-
BA 3932	Rhm	LIN-IC	CD Radio Cass., Stromversorgung/Power Supply		12-SILP			-
BA 3933	Rhm	LIN-IC	CD Radio Cass., Stromversorgung/Power Supply		12-SIL			-
BA 3935	Rhm	LIN-IC	CD Radio Cass., Stromversorgung/Power Supply		12-SIL			-
BA 3960	Rhm	Z-IC	1,5...21V/1.2A, 1,5...21V/0,9A		12-SIL			-
BA 4110	Rhm	LIN-IC	FM IF System, AFC, AGC, Ucc=6...12V		16-SQP			KA 22441, LA 1140
BA 4111	Rhm	LIN-IC	FM IF, AFC, AGC		16-DIP			-
BA 4111 F		LIN-IC	=BA 4111: SMD		16-MDIP			-
BA 4112	Rhm	LIN-IC	Cordless Telephone, FM IF, Schmalband/Narrow Band		16-DIP			-
BA 4113	Rhm	LIN-IC	Telecom, FM IF, Schmalband/Narrow Band		18-DIP			-
BA 4114	Rhm	LIN-IC	Telecom, FM IF, Schmalband/Narrow Band		16-DIP			-
BA 4210	Rhm	LIN-IC	AM/FM IF, Ucc=2,6...6V		16-DIP			-
BA 4210 F		LIN-IC	=BA 4210: SMD		16-MDIP			-
BA 4220	Rhm	LIN-IC	AM/FM IF, Demodulator, Ucc=3...14V		16-DIP			HA 12413, KA 2243
BA 4220 F		LIN-IC	=BA 4220: SMD		16-MDIP			-
BA 4222	Rhm	LIN-IC	AM/FM IF		16-DIP			-
BA 4224	Rhm	LIN-IC	AM HF, FM IF		16-DIP			-
BA 4224 F		LIN-IC	=BA 4224: SMD		16-MDIP			-

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
BA 4226	Rhm	LIN-IC	AM/FM IF	16-DIP			-
BA 4228 F		LIN-IC	=BA 4228L: SMD	16-MDIP			-
BA 4228 L	Rhm	LIN-IC	AM HF, AM/FM IF	16-SQP			-
BA 4230 AF	Rhm	LIN-IC	SMD, AM/FM IF System, Ucc=1,5(1…2)V	18-MDIP			-
BA 4230 AFS		LIN-IC	=BA 4230AF:	20-SMDIP			-
BA 4236 L	Rhm	LIN-IC	AM/FM IF (Upper Heterodyne), Ucc=6(2,7…12)V	18-SQP			-
BA 4237 L	Rhm	LIN-IC	AM/FM IF (Lower Heterodyne), Ucc=6(2,7…12)V	18-SQP			-
BA 4240 F		LIN-IC	=BA 4240L: SMD	18-MDIP			-
BA 4240 L	Rhm	LIN-IC	AM/FM IF System, Ucc=3(1,7…4,5)V	18-SQP			-
BA 4260	Rhm	LIN-IC	AM Tuner, FM IF	16-DIP	LA 1260	16-DIP	KA 2247, LA 1260
BA 4402(L)	Rhm	LIN-IC	FM Radio, Front End, Ucc=1,8…9V	9-SIP			-
BA 4403	Rhm	LIN-IC	FM Radio, Front End, Ucc=1,8…9V	7-SIP			-
BA 4404	Rhm	LIN-IC	FM Radio, Front End, Ucc=1,8…9V	9-SIP			-
BA 4405	Rhm	LIN-IC	FM Radio, Front End, Ucc=1,8…9V	7-SIP			-
BA 4408 F	Rhm	LIN-IC	SMD, FM Radio, Front End, Ucc=1,5(0,9…2)V	14-MDIP			-
BA 4411	Rhm	LIN-IC	FM Radio, Front End, Ucc=2…8V	9-SIP			-
BA 4412	Rhm	LIN-IC	FM Radio, Front End, Ucc=2…8V	9-SIP			-
BA 4413	Rhm	LIN-IC	FM Radio, Front End, Ucc=2…8V	9-SIP			-
BA 4422 AN	Rhm	LIN-IC	FM/TV Front End, Ucc=2,4…5,5V	9-SIP			KIA 6058S
BA 4424 N	Rhm	LIN-IC	FM/TV Front End, Ucc=1,6…6V, …225MHz	9-SIP			-
BA 4425 F	Rhm	LIN-IC	FM/TV Front End, Ucc=1,6…6V, …225MHz	8-MDIP			-
BA 4510 F	Rhm	OP-IC	SMD, Dual, ±5V, 9MHz, 5V/µs, -20…+75°	8-MDIP			-
BA 4558	Rhm	OP-IC	Dual, Serie 158, ±18V, -20…+75°	8-DIP	4558/8-D	8-DIP	… 158…, … 258…, … 1458…, … 4558…
BA 4558 F		OP-IC	=BA 4558: SMD	8-MDIP			… 158…, … 258…, … 1458…, … 4558…
BA 4558 N		OP-IC	=BA 4558:Fig. ›	8-SIP			… 158…, … 258…, … 1458…, …4558…
BA 4560	Rhm	OP-IC	Dual, hi-current, ±18V, 4V/µs, 10MHz, -20…+75°	8-DIP			-
BA 4560 F		OP-IC	=BA 4560: SMD	8-MDIP			-
BA 4560 N		OP-IC	=BA 4560:Fig. ›	8-SIP			-
BA 5101	Rhm	LIN-IC	Recorder, Switchless Rec/Play Amp., ALC, Ucc=6…9V	16-SQP			-
BA 5102(A)	Rhm	LIN-IC	VC, Audio Rec/Play Amp., Logic, 9 & 12V	18-DIP	BA 5102 A	18-DIP	KA 2983
BA 5102(A)F		LIN-IC	=BA 5102(A): SMD	18-MDIP			-
BA 5102(A)L		LIN-IC	=BA 5102(A): Fig. ›	18-SQP			-
BA 5104 A	Rhm	LIN-IC	Recorder, Switchless, Rec/Play Amp., Ucc=6…9V	16-SQP			(BA 5101)
BA 5112 LS	Rhm	LIN-IC	VC, Switchless Audio Rec/Play Amp.	24-SQP			-
BA 5114 LS	Rhm	LIN-IC	VC, Switchless Audio Rec/Play Amp., Ucc=4,5…13V	24-SQP			-
BA 5115	Rhm	LIN-IC	VC, Switchless Audio Rec/Play Amp., Ucc=4…13V	18-DIP			-
BA 5115 L		LIN-IC	=BA 5115: Fig. ›	18-SQP			-
BA 5116	Rhm	LIN-IC	VC, Switchless Audio Rec/Play Amp., Ucc=4…13V	20-DIP			-
BA 5117 L	Rhm	LIN-IC	VC, Switchless Audio Rec/Play Amp., Ucc=4…13V	18-SQP			-
BA 5152 F	Rhm	LIN-IC	SMD, HiFi Stereo Kopfh./Headphone Amp., Ucc=1,5V	16-MDIP			-
BA 5204	Rhm	LIN-IC	Dual Kopfh.-Verst/Headphone Amp., 35mW(32Ω), 3V	16-SQP			-
BA 5204 F		LIN-IC	=BA 5204: SMD	16-MDIP			-
BA 5206 F,BF	Rhm	LIN-IC	SMD, Dual Kopfh./Headphone Amp., 64mW(16Ω), 3V	16-MDIP			-
BA 5214	Rhm	LIN-IC	Dual Kopfh.-Verst/Headphone Amp., 35mW(32Ω), 3V	16-DIP			-
BA 5302 A	Rhm	LIN-IC	2x Audio Out, 13V, 2x2,4W(9V/4Ω)	12-DIP+b			BA 5304
BA 5304	Rhm	LIN-IC	2x Audio Out, 2x3W(9V/3Ω)	12-DIP+b			-
BA 5402	Rhm	LIN-IC	2x Audio Out, 18V, 2x4,2W(12V/4Ω)	12-SILP			BA 536, BA 5406
BA 5402 A		LIN-IC	=BA 5402: In	12-SILP			BA 536, BA 5406
BA 5404	Rhm	LIN-IC	Audio Out, 20V, 0,36W(12V/32Ω)	9-SIP			-
BA 5406	Rhm	LIN-IC	2x Audio Out, 18V, 2x5W(12V/3Ω)	12-SILP			BA 536, BA 5402(A), KIA 6283K
BA 5410	Rhm	LIN-IC	2x Audio Out, 20V, 2x5,2W(12V/3Ω)	10-SIL	BA 5410	10-SIL	-
BA 5412	Rhm	LIN-IC	Audio Out, 24V, 2x5,4W(12V/3Ω)	12-SILP			-
BA 5413		LIN-IC	=BA 5412:Fig. ›	12-SIL			-
BA 6104	Rhm	LIN-IC	LED Linear Meter Drv, 5 LED, Ucc=12V	9-SIP			-
BA 6109	Rhm	LIN-IC	VC, Motor Drv (reversible), Ucc=6…18V, 0,8A	10-SIL	BA 6109	10-SIL	BA 6209
BA 6110	Rhm	OP-IC	Voltg. Controlled, 34V, -20…+70°	9-SIP			-
BA 6110 FS		OP-IC	=BA 6110: SMD	16-SMDIP			-
BA 6118	Rhm	LIN-IC	Motorsteuerung/Motor Control, 4,8V	14-DIP			-
BA 6121	Rhm	LIN-IC	VC-Logik (4 Sign.)	16-DIP			-
BA 6121 F		LIN-IC	=BA 6121: SMD	16-MDIP			-
BA 6122 A	Rhm	LIN-IC	VC PS, S-Reg. 5V, Stop-Function, Error Amp.	16-SQP			-
BA 6122 AF		LIN-IC	=BA 6122(A): SMD	16-MDIP			-
BA 6124	Rhm	LIN-IC	LED VU-Meter Drv, 5 LED, Ucc=6(3,5…16)V	9-SIP			AN 6884, KA 2284, LB 1403, KIA 6966S
BA 6124 F		LIN-IC	=BA 6124: SMD	14-MDIP			-
BA 6125	Rhm	LIN-IC	LED Linear Meter Drv, 5 LED, Ucc=6(3,5…16)V	9-SIP			KA 2287, LB 1433, (BA 6124)
BA 6129 F	Rhm	LIN-IC	SMD, Reset IC with Battery Backup Function	8-MDIP			-
BA 6135	Rhm	LIN-IC	VC, Sensor	14-DIP			-
BA 6137	Rhm	LIN-IC	LED VU-Meter Drv, 5 LED, Ucc=6(3,5…16)V	9-SIP			KA 2285, LB 1423, KIA 6966S, (BA 6144)
BA 6138	Rhm	LIN-IC	2x Compression Amp. f. Level-Meter, Ucc=8,5…16V	9-SIP			-
BA 6138 F		LIN-IC	=BA 6138: SMD	14-MDIP			-
BA 6139(L)	Rhm	LIN-IC	7-Bit FLT Display Drv, Ucc=24V	16-SQP			-
BA 6144	Rhm	LIN-IC	LED VU-Meter Drv, 5 LED, Ucc=12(3,5…16)V	9-SIP			(BA 6137)
BA 6146	Rhm	LIN-IC	12P. VU-Meter Drv(FLT Display), Ucc=7,5…20V	16-DIP			-
BA 6149 LS	Rhm	LIN-IC	S-Reg, 6 Ausg.-Spg./Output Voltages	24-SQP			-
BA 6154	Rhm	LIN-IC	LED VU-Meter Drv, 5 LED, Ucc=6(3,5…16)V	9-SIP			(BA 6137, BA 6144)
BA 6155 CH-2W	Rhm	OPTO-IC	Photo Sensor, Schmitt-Trigger	Chip			-
BA 6161 F		LIN-IC	=BA 6161: SMD	8-MDIP			-
BA 6161 N	Rhm	LIN-IC	S-Reg f. Electronic Tuner, 30…45V, ±1mV/°C	5-SIP			-
BA 6162	Rhm	LIN-IC	Reset IC with Battery Backup Function	8-MDIP			-
BA 6162 F		LIN-IC	=BA 6162: SMD	8-DIP			-
BA 6191	Rhm	LIN-IC	CD, 2 Channel Motor Drv(reversible), 7…16V	12-SIL			-
BA 6208	Rhm	LIN-IC	Motor Drv (reversible), Ucc=4,5…15V, 0,5A	9-SIP			-
BA 6208 F		LIN-IC	=BA 6208: SMD	8-MDIP			-
BA 6209	Rhm	LIN-IC	VC, Motor Drv (reversible), 6…18V, 1,6A	10-SIL	BA 6209	10-SIL	KA 8301
BA 6209 N		LIN-IC	=BA 6209: Fig. ›	10-SIP			-
BA 6212	Rhm	LIN-IC	8x Uni Drv, hi-current, 7V, 0,4A	20-DIP			-
BA 6218	Rhm	LIN-IC	Motor Drv (reversible), Ucc=4,5…15V, 0,7A	9-SIP			-
BA 6219 B	Rhm	LIN-IC	VC, Motor Drv (reversible), Ucc=8…18V, 2,2A	10-SIL			-
BA 6219 BFP-Y		LIN-IC	=BA 6219: SMD	25-SMDIP+b			-
BA 6220	Rhm	LIN-IC	DC Motorreg./Electronic Governor, Ucc=3,6…16V	8-DIP			-
BA 6222	Rhm	LIN-IC	VC, Motor Drv (reversible), Ucc=8…18V, 2,2A	10-SIL	BA 6222	10-SIL	-
BA 6227	Rhm	LIN-IC	DC Motorregler/Electronic Governor, Ucc=3V	8-DIP			-
BA 6229	Rhm	LIN-IC	Motor Drv (reversible), Ucc=8…23V, 1,2A	10-SIL			-

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
BA 6235	Rhm	LIN-IC	DC Motorregler/Electronic Governor, Ucc=3(1,8…5)V	8-DIP			-
BA 6235 F		LIN-IC	=BA 6235: SMD	8-MDIP			-
BA 6238 A	Rhm	LIN-IC	VC++, Motor Drv (reversible), Ucc=8…18V, 1,6A	10-SIL			KA 8305
BA 6238 AN		LIN-IC	=BA 6238A: Fig. →	10-SIP			-
BA 6239 A	Rhm	LIN-IC	VC++, Motor Drv (reversible), Ucc=8…18V, 1,2A	10-SIL			-
BA 6239 AN		LIN-IC	=BA 6239A: Fig. →	10-SIP			-
BA 6240	Rhm	LIN-IC	DC Motorregler/Electronic Governor, Ucc=3,5…14V	8-DIP			-
BA 6246	Rhm	LIN-IC	2x Motor Drv (reversible), Ucc=8…18V, 1A, 2W	10-SIL			-
BA 6246 N		LIN-IC	=BA 6246: 1W, Fig. →	10-SIP			-
BA 6247	Rhm	LIN-IC	2x Motor Drv (reversible), Ucc=8…18V, 1A, 2W	10-SIL	BA 6247	10-SIL	-
BA 6247 FP-Y		LIN-IC	=BA 6247: SMD, 1,45W	25-SMDIP+b			-
BA 6247 N		LIN-IC	=BA 6247: 1W, Fig. →	10-SIP			-
BA 6248	Rhm	LIN-IC	2x Motor Drv(reversible), 1,6A	10-SIL			-
BA 6249	Rhm	LIN-IC	2x Motor Drv (reversible), Ucc=8…18V, 1A, 2W	10-SIL			-
BA 6249 N		LIN-IC	=BA 6249: 1W, Fig. →	10-SIP			-
BA 6250	Rhm	LIN-IC	7x PNP Darl.-Transistor, 30V, 20mA	16-DIP			-
BA 6250 F		LIN-IC	=BA 6250: SMD	16-MDIP			-
BA 6251	Rhm	LIN-IC	7x PNP Darl.-Transistor, 30V, 20mA	16-DIP			-
BA 6251 F		LIN-IC	=BA 6251: SMD	16-MDIP			-
BA 6256	Rhm	LIN-IC	6x Uni Drv, Ucc=3…10V, 0,4A, Usat=0,6V(0,4A)	16-DIP			-
BA 6257	Rhm	LIN-IC	7x PNP Darl. Drv, Ucc=20V, 0,1A, Usat<2,2V(75mA)	16-DIP			-
BA 6259 N	Rhm	LIN-IC	2x Motor Drv (reversible), Ucc=8…18V, <1A, 1W	10-SIP			-
BA 6266	Rhm	LIN-IC	Hex Inverter, Ucc=5V, OC Out	14-DIP			-
BA 6266 F		LIN-IC	=BA 6266: SMD	14-MDIP			-
BA 6267	Rhm	LIN-IC	Hex Buffer, Driver, Ucc=5V	14-DIP			SN 7417
BA 6267 F		LIN-IC	=BA 6267: SMD	14-MDIP			-
BA 6280 AF	Rhm	LIN-IC	SMD, CD, PWM Motor Drv	22-MDIP			KA 9255D
BA 6281 F	Rhm	LIN-IC	SMD, CD, PWM Motor Drv	24-MDIP			-
BA 6285 FP	Rhm	LIN-IC	SMD, VC++,Motor Drv (reversible), Ucc=4,5…15V, 1A	25-SMDIP+b			-
BA 6285 FS		LIN-IC	=BA 6285FP: Fig. →	16-SMDIP			-
BA 6286	Rhm	LIN-IC	VC++, Motor Drv (reversible), Ucc=4,5…15V, 1A	10-SIL			-
BA 6286 N		LIN-IC	=BA 6286: Fig. →	10-SIP			-
BA 6287 F	Rhm	LIN-IC	SMD, VC++,Motor Drv (reversible), Ucc=4,5…15V, 1A	8-MDIP			-
BA 6288 FS	Rhm	LIN-IC	SMD, VC++,Motor Drv (reversible), Ucc=3,5…15V, 1A	16-SMDIP			-
BA 6289 F	Rhm	LIN-IC	SMD, Motor Drv (reversible), Ucc=3,5…15V, 0,6/2A	8-MDIP			BA 6417F
BA 6290 A	Rhm	LIN-IC	CD, 2x BTL Power Drv, Ucc=12V, Io=0,5A (OP-Amp.)	12-SILP			KA 9257
BA 6292	Rhm	LIN-IC	CD, 2x BTL Power Drv, Ucc=12V, Io=0,5A	12-SILP			-
BA 6294	Rhm	LIN-IC	CD, 2x BTL Power Drv, Ucc=12V	10-SIL			-
BA 6295 FP,AFP	Rhm	LIN-IC	SMD, CD, 2x BTL Power Drv, Ucc=7,5…18V, Io=1A	28-SMDIP+b			-
BA 6296 FP	Rhm	LIN-IC	SMD, CD, 4x BTL Power Drv, Ucc=8(6…9)V	28-SMDIP+b			-
BA 6297 AFP	Rhm	LIN-IC	SMD, CD, 4x BTL Power Drv, Ucc=8(6…9)V	28-SMDIP+b			-
BA 6299 FP	Rhm	LIN-IC	SMD, CD, 4x H-Bridge BTL Power Drv, Ucc=6…11V	28-SMDIP+b			-
BA 6301	Rhm	LIN-IC	VC, Speed Servo Ctrl., FG System, Ucc=4,5…13V	16-DIP			-
BA 6301 F		LIN-IC	=BA 6301: SMD	16-MDIP			-
BA 6302(A)	Rhm	LIN-IC	VC, Speed Servo Ctrl., FG System, Ucc=4,5…13V	16-DIP			-
BA 6302(A)F		LIN-IC	=BA 6302: SMD	16-MDIP			-
BA 6303	Rhm	LIN-IC	VC, Speed Servo Ctrl., FG System, Ucc=4,5…13V	16-DIP			-
BA 6303 F		LIN-IC	=BA 6303: SMD	16-MDIP			-
BA 6304	Rhm	LIN-IC	VC-Drahtfernbed./wire remote ctrl.	14-DIP			-
BA 6305	Rhm	LIN-IC	VC, Servo, FG/CTL/DTP-Verst./Amp., Ucc=4,5…13V	8-SIP			-
BA 6305 F		LIN-IC	=BA 6305: SMD	8-MDIP			-
BA 6320	Rhm	LIN-IC	VC, Power Hold	16-SOP			-
BA 6321	Rhm	LIN-IC	VC, Speed Servo Ctrl., FG System, Ucc=4,5…13V	16-DIP			-
BA 6325 F	Rhm	LIN-IC	VC(8mm), Sensor, Ucc=4,25…13V, 2,5mA	24-MDIP			-
BA 6334	Rhm	LIN-IC	VC/TV++, 16-Operation Mode Detector	9-SIP			-
BA 6340	Rhm	LIN-IC	IR-FB, Encoder, Ucc=4,75…12,5V	8-SIP			-
BA 6351 S	Rhm	LIN-IC	CD, Analog Servo	42-SDIP			-
BA 6353 S	Rhm	LIN-IC	CD, Analog Servo, Ucc=±5(±4,5…±7,5)V	42-SDIP			-
BA 6360	Rhm	LIN-IC	VC, Bandende/Tape End Sensor	14-DIP			-
BA 6392 FP	Rhm	LIN-IC	SMD, CD, 4x BTL Power Drv, Ucc=6…16V	28-SMDIP+b			-
BA 6393 FP	Rhm	LIN-IC	SMD, CD, 4x BTL Power Drv, Ucc=6…9V	28-SMDIP+b			-
BA 6394 FP	Rhm	LIN-IC	SMD, CD, 4x H-Bridge BTL Power Drv, Ucc=3…11V	28-SMDIP+b			-
BA 6395 AFP	Rhm	LIN-IC	SMD, CD, 5x BTL Power Drv, Ucc=6…12V	28-SMDIP+b			-
BA 6396 FP	Rhm	LIN-IC	SMD, CD, 4x BTL Power Drv, Ucc=6…9V	28-SDIP+b			-
BA 6397 FP	Rhm	LIN-IC	SMD, CD, 4x BTL Power Drv, Ucc=6…9V	28-SMDIP+b			-
BA 6398 FP	Rhm	LIN-IC	SMD, CD, 4x BTL Power Drv, Ucc=6…9V	28-SMDIP+b			-
BA 6399 FP	Rhm	LIN-IC	SMD, CD, 4x H-Bridge BTL Power Drv, Ucc=6…11V	28-SMDIP+b			-
BA 6402 F		LIN-IC	=BA 6412: SMD	8-MDIP			-
BA 6404	Rhm	LIN-IC	Fan Motor Pre-Drv, 2-Phase Half-wave, Ucc=4…28V	8-DIP			-
BA 6404 F		LIN-IC	=BA 6404: SMD	8-MDIP			-
BA 6405	Rhm	LIN-IC	VC, Servo, FG/CTL-Verst./Amp., Ucc=4,5…6V	14-DIP			-
BA 6405 F		LIN-IC	=BA 6405: SMD	14-MDIP			-
BA 6406	Rhm	LIN-IC	Fan Motor Pre-Drv, 2-Phase Half-wave, Ucc=4…28V	8-DIP			-
BA 6406 F		LIN-IC	=BA 6406: SMD	8-MDIP			-
BA 6407	Rhm	LIN-IC	Fan Motor Drv, 2-Phase Half-wave, Ucc=5…14,5V	8-DIP			-
BA 6407 F		LIN-IC	=BA 6407: SMD	8-MDIP			-
BA 6408 FS	Rhm	LIN-IC	Fan Motor Drv, 2-Phase Half-wave, Ucc=5…14,5V	16-SMDIP			-
BA 6411	Rhm	LIN-IC	VC++, 2-Phase DD Motor Drv, Ucc=9…18V	12-SIL			KA 8304
BA 6411 FP		LIN-IC	=BA 6411: SMD	28-SMDIP+b			-
BA 6412	Rhm	LIN-IC	Fan Motor Pre-Drv, 2-Phase Half-wave, Ucc=4…28V	8-DIP			-
BA 6413	Rhm	LIN-IC	CD/VC++, 2-Phase DD Motor Drv	12-SIL			-
BA 6414 FP-Y	Rhm	LIN-IC	SMD, VC, 2-Phase DD Cylinder Motor Drv, Ucc=8…20V	25-SMDIP+b			-
BA 6414 FS	Rhm	LIN-IC	=BA 6414FP-Y:	24-SMDIP			-
BA 6417 F	Rhm	LIN-IC	=BA 6289F: 1,0/3,0A	8-MDIP			-
BA 6418 N	Rhm	LIN-IC	Motor Drv(reversible), Ucc=4,5…15V, 0,7A	9-SIP			-
BA 6424 FS	Rhm	LIN-IC	SMD, Fan Motor Drv, 1-phase Full Wave, Ucc=6…28V	16-SMDIP			-
BA 6431 F		LIN-IC	=BA 6431S: SMD	28-MDIP			-
BA 6431 S	Rhm	LIN-IC	VC, 3-Phase DD Motor Drv (Capstan)	24-DILP			-
BA 6432 S	Rhm	LIN-IC	VC, 3-Phase DD Capstan Motor Drv, Ucc=4…6V	24-DILP			-
BA 6435 S	Rhm	LIN-IC	VC, 3-Phase Capstan Motor Drv, Ucc=4…6V	24-DILP			-
BA 6436 P	Rhm	LIN-IC	VC, 3-Phase Capstan Motor Drv, Ucc=4…6V	24-DILP			-
BA 6437 S	Rhm	LIN-IC	VC, 3-Phase Capstan Motor Drv, Ucc=4…6V	24-DILP			-
BA 6438 S	Rhm	LIN-IC	VC, 3-Phase Capstan Motor Drv, Ucc=4…6V	24-DILP			-

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
BA 6439 P,S	Rhm	LIN-IC	VC, 3-Phase Capstan Motor Drv, Ucc=4…6/3…23V		24-DILP			-
BA 6440 FP	Rhm	LIN-IC	SMD, VC,DAT, 3-Phase Capstan Motor Drv, Ucc=4…6V		28-SMDIP+b			-
BA 6441 FP	Rhm	LIN-IC	SMD, VC,DAT, 3-Phase Capstan Motor Drv, Ucc=4…6V		28-SMDIP+b			-
BA 6450 F	Rhm	LIN-IC	SMD, VC, 3-Phasen DD Motor Drv (Cylinder)		24-MDIP			-
BA 6453 FP	Rhm	LIN-IC	SMD, VC, 3-Phase DD Motor Drv		24-SMDIP			-
BA 6455 FS	Rhm	LIN-IC	SMD, VC, 3-Phase Full Wave Cylinder Motor Drv		24-MDIP			-
BA 6456 FS	Rhm	LIN-IC	SMD, VC, 3-Phase Cylinder Motor Drv, Ucc=4,5…5,5V		24-MDIP			-
BA 6457 P	Rhm	LIN-IC	SMD, VC, 3-Phase DD Motor Drv		24-SMDIP			-
BA 6458 FP	Rhm	LIN-IC	SMD, VC, 3-Phase DD Cylinder Motor Drv, 4,25…5,5V		24-SMDIP			-
BA 6458 FP-Y		LIN-IC	=BA 6458FP:		25-SMDIP+b			-
BA 6459 FS		LIN-IC	=BA 6459P,S: SMD		24-SMDIP			-
BA 6459 P,S	Rhm	LIN-IC	VC, 3-Phase DD Cylinder Motor Drv, Ucc=4,5…5,5V		24-DILP			-
BA 6462 FP	Rhm	LIN-IC	SMD, VC, 3-Phase Cylinder Motor Drv, 4,25…5,5V		24-SMDIP+b			-
BA 6463 FP-Y	Rhm	LIN-IC	SMD, VC, 3-Phase Cylinder Motor Drv, Ucc=7,3…23V		25-SMDIP+b			-
BA 6465 FP-Y	Rhm	LIN-IC	SMD,FDD, 3-Phase Spindle Motor Drv, Ucc=4,25…5,5V		25-SMDIP+b			-
BA 6470 FP	Rhm	LIN-IC	3,5" FDD, 3-Phase Spindle Motor Drv, Ucc=4,2…6V		24-SMDIP+b			-
BA 6471 FP	Rhm	LIN-IC	3,5" FDD, 3-Phase Spindle Motor Drv,Ucc=4,25…6,5V		24-SMDIP+b			-
BA 6472 FP	Rhm	LIN-IC	3,5" FDD, 3-Phase Spindle Motor Drv,Ucc=4,25…6,5V		24-SMDIP+b			-
BA 6473 FP	Rhm	LIN-IC	3,5" FDD, 3-Phase Spindle Motor Drv,Ucc=4,25…6,5V		24-SMDIP+b			-
BA 6473 FP-Y		LIN-IC	=BA 6473FP: Fig. ›		25-SMDIP+b			-
BA 6474 FP	Rhm	LIN-IC	3,5" FDD, 3-Phase Spindle Motor Drv		24-SMDIP+b			-
BA 6475 FP	Rhm	LIN-IC	FDD, 3-Phase Spindle Motor Drv, Ucc=5+12V		24-SMDIP+b			-
BA 6476 FP	Rhm	LIN-IC	FDD, 3-Phase Spindle Motor Drv, Ucc=4,2…6,5V		24-SMDIP+b			-
BA 6476(A)FP-Y		LIN-IC	=BA 6476FP: Fig. ›		25-SMDIP+b			-
BA 6479 AFP-Y	Rhm	LIN-IC	FDD, 3-Phase Spindle Motor Drv, Ucc=4,2…6,5V		25-SMDIP+b			-
BA 6480 K	Rhm	LIN-IC	FDD, Spindle/Stepper Motor Drv, Ucc=5V		44-MP			-
BA 6485 FP-Y	Rhm	LIN-IC	FDD, 3-Phase Spindle Motor Drv, Ucc=4,2…6,5V		25-SMDIP+b			-
BA 6487 FP-Y	Rhm	LIN-IC	FDD, 3-Phase Spindle Motor Drv, Ucc=9…13,2V		25-SMDIP+b			-
BA 6488 FP-Y	Rhm	LIN-IC	FDD, 3-Phase Spindle Motor Drv, Ucc=9…13,2V		25-SMDIP+b			-
BA 6490 FS	Rhm	LIN-IC	FDD, 3-Phase Spindle Motor Drv, Ucc=4,2…6,5V		32-SMDIP			-
BA 6491 FS	Rhm	LIN-IC	FDD, 3-Phase Spindle Motor Drv, Ucc=4,2…6,5V		32-SMDIP			-
BA 6522	Rhm	OP-IC	Dual, hi-speed		8-DIP			-
BA 6522 F		OP-IC	=BA 6522: SMD		8-MDIP			-
BA 6527 A	Rhm	LIN-IC	Telecom, Leak Breaker, Minute Signal Detect		8-SIP			-
BA 6562	Rhm	LIN-IC	Telecom, Sprechkreis/Speech Network		16-DIP			-
BA 6562 F		LIN-IC	=BA 6562: SMD		18-MDIP			-
BA 6564 A	Rhm	LIN-IC	Telecom, Wecker/Tone Ringer		8-DIP			-
BA 6564 AF		LIN-IC	=BA 6564A: SMD		8-MDIP			-
BA 6565 A	Rhm	LIN-IC	Telecom, Wecker/Tone Ringer		8-DIP			-
BA 6565 AF		LIN-IC	=BA 6565A: SMD		8-MDIP			-
BA 6566	Rhm	LIN-IC	Telecom, Sprechkreis/Speech Network		18-DIP			-
BA 6566 F		LIN-IC	=BA 6566: SMD		18-MDIP			-
BA 6566 FP		LIN-IC	=BA 6566: SMD		24-SMDIP+b			-
BA 6567 K	Rhm	LIN-IC	Telecom, Sprechkreis/Speech Network		44-MP			-
BA 6569 FP		LIN-IC	=BA 6569S: SMD		24-SMDIP+b			-
BA 6569 S	Rhm	LIN-IC	Telecom, Sprechkreis/Speech Network		22-SDIP			-
BA 6571 A	Rhm	LIN-IC	Telecom, Höhrerverst./Speaker Phone		28-DIP			-
BA 6571 AF		LIN-IC	=BA 6571A: SMD		28-MDIP			-
BA 6580 DK	Rhm	LIN-IC	FDD, Read/Write Amplifier		44-MP			-
BA 6587 K	Rhm	LIN-IC	FDD, Read/Write Amplifier		44-MP			-
BA 6588 K	Rhm	LIN-IC	FDD, Read/Write Amplifier		44-MP			-
BA 6589 K	Rhm	LIN-IC	FDD, 3",3,5",5" Read/Write Amp., Ucc=5+12V		44-MP			-
BA 6590 S	Rhm	LIN-IC	Centronics Interface		42-SDIP			-
BA 6600 K	Rhm	LIN-IC	FDD, Read/Write Amplifier, Ucc=5V		44-MP			-
BA 6607 K	Rhm	LIN-IC	FDD, Read/Write Amplifier, Ucc=5V		32-MP			-
BA 6610 AK	Rhm	LIN-IC	FDD, Read/Write Amplifier, Ucc=5V		32-MP			-
BA 6612 K	Rhm	LIN-IC	FDD, Read/Write Amplifier, Ucc=5V		32-MP			-
BA 6722	Rhm	LIN-IC	2x S-Reg, 5,2V/80mA, 5V/80mA		10-SIL			-
BA 6790 FP	Rhm	LIN-IC	SMD, CD, 4x BTL Power Drv, Ucc=6…9V		28-SMDIP+b			-
BA 6800 A	Rhm	LIN-IC	16-P. FLT VU-Meter Drv, Peak Hold,Ucc=5(4,5…5,8)V		28-DIP			-
BA 6800 AF		LIN-IC	=BA 6800A: SMD		28-MDIP			-
BA 6800 AS	Rhm	LIN-IC	16-P. FLT VU-Meter Drv, Peak Hold,Ucc=5(4,5…5,8)V		30-SDIP			-
BA 6803 S	Rhm	LIN-IC	16-P. FLT VU-Meter Drv, Peak Hold,Ucc=5(4,5…5,8)V		30-SDIP			-
BA 6805 A	Rhm	LIN-IC	16-P. FLT VU-Meter Drv, Peak Hold,Ucc=5(4,5…5,8)V		28-DIP			-
BA 6806 S	Rhm	LIN-IC	16-P. FLT VU-Meter Drv, Peak Hold,Ucc=5(4,5…5,8)V		30-SDIP			-
BA 6807	Rhm	LIN-IC	Fan Motor Drv, 2-Phase Half-wave, Ucc=5…14,5V		8-DIP			-
BA 6807 F		LIN-IC	=BA 6807: SMD		8-MDIP			-
BA 6808 FS	Rhm	LIN-IC	Fan Motor Drv, 2-Phase Half-wave, Ucc=5…14,5V		16-SMDIP			-
BA 6810 F		LIN-IC	=BA 6810S: SMD		28-MDIP			-
BA 6810 S	Rhm	LIN-IC	12P. FLT VU-Meter Drv, Peak Hold, Ucc=5(4,5…5,5)V		30-SDIP			-
BA 6820 F	Rhm	LIN-IC	SMD, 2x LED VU-Meter Drv, 12 LED, Ucc=5V		22-MDIP			-
BA 6822 F		LIN-IC	=BA 6822S: SMD		22-MDIP			-
BA 6822 S	Rhm	LIN-IC	2x LED VU-Meter Drv, 12 LED, Ucc=5V		22-SDIP			-
BA 6825 FS	Rhm	LIN-IC	SMD, VC, 2-Phase DD Cylinder Motor Drv, Ucc=8…20V		24-SMDIP			-
BA 6826 FS	Rhm	LIN-IC	SMD, VC, 2-Phase DD Cylinder Motor Drv, Ucc=8…20V		20-SMDIP			-
BA 6827 FS	Rhm	LIN-IC	SMD, VC, 2-Phase DD Cylinder Motor Drv, Ucc=8…20V		24-SMDIP			-
BA 6840 AFS	Rhm	LIN-IC	SMD, CD-ROM, 3-Phase Motor Drv, Ucc=4,25…5,5V		20-SMDIP			-
BA 6851 AFP-Y	Rhm	LIN-IC	Optical Disk, 3-Phase Spindle Motor Drv, Ucc=5V		25-SMDIP+b			-
BA 6885 FP	Rhm	LIN-IC	DC Motor Drv, Ucc=6,5…28V, 1,0/5,0A		24-SMDIP+b			-
BA 6885 FS		LIN-IC	=BA 6885FP: Fig. ›		16-SMDIP			-
BA 6886	Rhm	LIN-IC	DC Motor Drv, Ucc=6,5…28V, 1,0/5,0A		10-SIP			-
BA 6886 N		LIN-IC	=BA 6886: Fig. ›		10-SIL			-
BA 6890 FP	Rhm	LIN-IC	SMD, CD, 4x H-Bridge BTL Power Drv, Ucc=3…9V		28-SMDIP+b			-
BA 7001	Rhm	LIN-IC	VC++, Video Signal Switch, Ucc=12V		8-SIP			-
BA 7004	Rhm	LIN-IC	VC, Test Pattern Signal Generator		5-SIP	BA 7004*	5-SIP	-
BA 7004 F		LIN-IC	=BA 7004: SMD		8-MDIP			-
BA 7005	Rhm	LIN-IC	VC, Modulator		16-SQP			-
BA 7007(L)	Rhm	LIN-IC	VC, SECAM Discriminator		16-SQP			-
BA 7007 F		LIN-IC	=BA 7007: SMD		16-MDIP			-
BA 7021	Rhm	LIN-IC	TV,VC, Video Signal Switch, Ucc=5V		9-SIP			-
BA 7022 A	Rhm	LIN-IC	VC, 0,5H Skew Correction		22-DIP			-
BA 7023 L	Rhm	LIN-IC	VC, 0,5H Skew Detection		16-SQP			-
BA 7024	Rhm	LIN-IC	VC, TSG Video Switch, Ucc=4,5…6V		7-SIP			-

Original	Fabric.	Constr.	Info	Compl.	Fig.	JAEGER	Fig.	International
BA 7025 L	Rhm	LIN-IC	VC,TV, SECAM Discriminator		18-SQP			-
BA 7026 L	Rhm	LIN-IC	VC++, Audio/Video Signal Switch, mono DIN Standard		16-SQP			-
BA 7028 A	Rhm	LIN-IC	VC, Audio/Video Signal Switch, stereo DIN Standard		22-DIP			-
BA 7032 L	Rhm	LIN-IC	VC, Chroma Skew Correction		16-SQP			-
BA 7036 LS	Rhm	LIN-IC	VC, Special Playback (Noiseless Search)		24-SQP			-
BA 7039	Rhm	LIN-IC	VC(VHS), Auto Tracking Interface, Ucc=5V		16-DIP			-
BA 7042	Rhm	LIN-IC	VCO f. FM Intercom, FSK Modem, Wireless Mike, 5V		8-DIP			-
BA 7043 FS	Rhm	LIN-IC	SMD, VC(VHS), Auto Tracking Interface, Ucc=5V		20-SMDIP			-
BA 7044 N	Rhm	LIN-IC	VC, Testbild-/Test Pattern Generator		5-SIP			-
BA 7045	Rhm	LIN-IC	VC, NTSC ‣ PAL Convertion, Ucc=4,5...5,5V		16-DIP			-
BA 7045 FS		LIN-IC	=BA 7045: SMD		16-SMDIP			-
BA 7046	Rhm	LIN-IC	VC,TV, Sync. Signal Separation, AFC		8-DIP			-
BA 7046 F		LIN-IC	=BA 7046: SMD		8-MDIP			-
BA 7047 S	Rhm	LIN-IC	VC(VHS), Auto Tracking Interface, Ucc=5V		22-SDIP			-
BA 7048 N	Rhm	LIN-IC	VC(VHS), Auto Tracking Interface, Ucc=5V		10-SIP			-
BA 7049 FS		LIN-IC	=BA 7049S: SMD		24-SMDIP			-
BA 7049 S	Rhm	LIN-IC	VC(Multistandard), Chroma Signal Frequ. Converter		24-DILP			-
BA 7056 LS	Rhm	LIN-IC	VC++, HiFi Audio Output Switch, Ucc=7...13V		24-SQP			-
BA 7057 S	Rhm	LIN-IC	VC++, HiFi Audio Output Switch		22-SDIP			-
BA 7058 LS	Rhm	LIN-IC	VC++, HiFi Audio Output Switch, Ucc=7...13V		24-SQP			-
BA 7062 F	Rhm	LIN-IC	SMD, TV,VC, Sync. Signal Separation, AFC		8-MDIP			-
BA 7100	Rhm	LIN-IC	VC, SECAM Diskriminator		16-DIP			-
BA 7101	Rhm	LIN-IC	VC, Luminance Modulator		20-DIP			-
BA 7101 F		LIN-IC	=BA 7101: SMD		20-MDIP			-
BA 7103	Rhm	LIN-IC	VC, Luminance Modulator		20-DIP			-
BA 7103 F		LIN-IC	=BA 7103: SMD		20-MDIP			-
BA 7106 LS	Rhm	LIN-IC	VC, PAL/SECAM Detection, Delay Line Amp., Ucc=5V		24-SQP			-
BA 7107	Rhm	LIN-IC	VC(VHS), SECAM Chroma Signal Processor		28-DIP			-
BA 7107 F		LIN-IC	=BA 7107: SMD		28-MDIP			-
BA 7107 S		LIN-IC	=BA 7107: Fig. ‣		30-SDIP			-
BA 7115 L	Rhm	LIN-IC	Camera, Sucher-A/EVF Deflection		18-SQP			-
BA 7116	Rhm	LIN-IC	VC, Luminance Playback		20-DIP			-
BA 7116 F		LIN-IC	=BA 7116: SMD		20-MDIP			-
BA 7122 F		LIN-IC	=BA 7122L: SMD		16-MDIP			-
BA 7122 L	Rhm	LIN-IC	Camera, FPN Elimination f. MOS Camera		16-SQP			-
BA 7125 L	Rhm	LIN-IC	Camera, Sucher-Ablenkung/EVF Deflection		18-SQP			-
BA 7131 F	Rhm	LIN-IC	SMD, TV,VC, Video Signal Switch, Ucc=5V		8-MDIP			-
BA 7135 L	Rhm	LIN-IC	SMD, Camera, Sucher-A/EVF Deflection, Ucc=5V		18-MDIP			-
BA 7145 F	Rhm	LIN-IC	SMD, Camera, Sucher-A/EVF Deflection		16-MDIP			-
BA 7149 F	Rhm	LIN-IC	SMD, Camcorder, Sucher-A/EVF Deflection		16-MDIP			-
BA 7172 FS		LIN-IC	=BA 7172S: SMD		24-SMDIP			-
BA 7172 S	Rhm	LIN-IC	VC, Video Signal 2-Ch. Pre/Rec. Amp.		22-SDIP			-
BA 7212 S	Rhm	LIN-IC	VC, 2-Channel Video Signal Rec/Play Amp.		22-SDIP			-
BA 7230 LS	Rhm	LIN-IC	TV,Camera, RGB Encoder f. NTSC		24-SQP			-
BA 7244 BS	Rhm	LIN-IC	VC, 4-Channel Video Signal Rec/Play Amp.		32-SDIP			-
BA 7252 S	Rhm	LIN-IC	VC, 2-Channel Video Signal Rec/Play Amp.		22-SDIP			-
BA 7253 S	Rhm	LIN-IC	VC, 3-Channel Video Signal Rec/Play Amp.		22-SDIP			-
BA 7254 S	Rhm	LIN-IC	VC, 4-Channel Video Signal Rec/Play Amp.		32-SDIP			-
BA 7258 BS,CS	Rhm	LIN-IC	VC, Luminance Signal Processor		32-SDIP			-
BA 7258 AK		LIN-IC	=BA 7258AS: SMD		44-MP			-
BA 7258 AS	Rhm	LIN-IC	VC, Luminance Signal Processor		32-SDIP			-
BA 7266 F		LIN-IC	=BA 7266S: SMD		22-MDIP			-
BA 7266 S	Rhm	LIN-IC	VC, Color Signal Processor f. APC		22-SDIP			-
BA 7267 F		LIN-IC	=BA 7267S: SMD		22-MDIP			-
BA 7267 S	Rhm	LIN-IC	VC, Color Signal Processor f. APC		22-SDIP			-
BA 7274 S	Rhm	LIN-IC	VC, 4-Channel Video Signal Rec/Play Amp.		32-SDIP			-
BA 7277 S	Rhm	LIN-IC	VC, 4-Channel Video Signal Rec/Play Amp.		32-SDIP			-
BA 7279 S	Rhm	LIN-IC	VC, 4-Channel Video Signal Rec/Play Amp.		32-SDIP			-
BA 7280 AS	Rhm	LIN-IC	VC, Luminance Signal Processor		32-SDIP			-
BA 7281 BS	Rhm	LIN-IC	VC, Luminance Signal Processor		32-SDIP			-
BA 7288 K	Rhm	LIN-IC	VC, Luminance Signal Processor		44-MP			-
BA 7602	Rhm	LIN-IC	TV,VC, 3x Video Signal Switch, Ucc=5V		16-DIP			-
BA 7602 F		LIN-IC	=BA 7602: SMD		16-MDIP			-
BA 7603	Rhm	LIN-IC	TV,VC, 3x Video Signal Switch, Ucc=5V		16-DIP			-
BA 7603 F		LIN-IC	=BA 7603: SMD		16-MDIP			-
BA 7604 N	Rhm	LIN-IC	TV,VC, 2x Video Signal Switch, Ucc=5V		10-SIP			-
BA 7605 N	Rhm	LIN-IC	TV,VC, 2x Video Signal Switch, Ucc=5V		10-SIP			-
BA 7606	Rhm	LIN-IC	TV,VC, 3x Video Signal Switch, Ucc=5V		16-DIP			-
BA 7606 F		LIN-IC	=BA 7606: SMD		16-MDIP			-
BA 7607	Rhm	LIN-IC	TV,VC, 3x Video Signal Switch, Ucc=5V		16-DIP			-
BA 7607 F		LIN-IC	=BA 7606: SMD		16-MDIP			-
BA 7608 N	Rhm	LIN-IC	TV,VC, 2x Video Signal Switch, Ucc=5V		10-SIP			-
BA 7609	Rhm	LIN-IC	TV,VC, 3x Video Signal Switch, Ucc=5V		16-DIP			-
BA 7609 F		LIN-IC	=BA 7609: SMD		16-MDIP			-
BA 7611 N,AN	Rhm	LIN-IC	TV,VC, Video Signal Switch, Ucc=5V		8-SIP			-
BA 7612 N	Rhm	LIN-IC	TV,VC, Video Signal Switch, Ucc=5V		8-SIP			-
BA 7613 N	Rhm	LIN-IC	TV,VC, Video Signal Switch, Ucc=5V		8-SIP			-
BA 7625	Rhm	LIN-IC	VC, 2xVideo Signal Switch f. Rec/Play Amp., Ucc=5V		16-DIP			-
BA 7626	Rhm	LIN-IC	VC, 2xVideo Signal Switch f. Rec/Play Amp., Ucc=5V		16-DIP			-
BA 7630 F		LIN-IC	=BA 7630S: SMD		28-MDIP			-
BA 7630 S	Rhm	LIN-IC	VC, SECAM Switch f. Scrambled Broadcasting		22-SDIP			-
BA 7631	Rhm	LIN-IC	VC, Switch f. Scrambled Broadcasting		16-DIP			-
BA 7631 F		LIN-IC	=BA 7631: SMD		16-MDIP			-
BA 7644 AN	Rhm	LIN-IC	TV,VC, Video Signal Switch, Ucc=5V		10-SIP			-
BA 7645 N	Rhm	LIN-IC	TV,VC, Video Signal Switch, Ucc=5V		10-SIP			-
BA 7649 A	Rhm	LIN-IC	TV,VC, Video Signal Switch, Ucc=5V		14-DIP			-
BA 7649 AF		LIN-IC	=BA 4679A: SMD		14-MDIP			-
BA 7655 A	Rhm	LIN-IC	Camcorder,VC, 2x VCA(Voltage Controlled Amp.)		8-DIP			-
BA 7655 AF		LIN-IC	=BA 7655: SMD		8-MDIP			-
BA 7700 K1	Rhm	LIN-IC	VC(VHS), HiFi Audio Signal Processor		80-MP			-
BA 7703 K1	Rhm	LIN-IC	VC(VHS), HiFi Audio Signal Processor		80-MP			-
BA 7705 K1	Rhm	LIN-IC	VC(VHS), HiFi Audio Signal Processor		80-MP			-
BA 7706 KS	Rhm	LIN-IC	VC(VHS), HiFi Audio Signal Processor		80-MP			-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BA 7710 S	Rhm	LIN-IC	VC, HiFi Audio FM Modem		30-SDIP				-
BA 7711 S	Rhm	LIN-IC	VC, HiFi Audio FM Modem		30-SDIP				-
BA 7720 S	Rhm	LIN-IC	VC++, HiFi Audio Peak Noise Reduction		42-SDIP				-
BA 7721 S	Rhm	LIN-IC	VC++, HiFi Audio Peak Noise Reduction		42-SDIP				-
BA 7725 FS		LIN-IC	=BA 7725S: SMD		20-SMDIP				-
BA 7725 S	Rhm	LIN-IC	Audio Compression/Expanding f. Karaoke Systems		22-SDIP				-
BA 7730 S	Rhm	LIN-IC	VC++, HiFi Audio, Input/Output Switch, Ucc=7…13V		32-SDIP				-
BA 7731 S	Rhm	LIN-IC	VC++, HiFi Audio, Input/Output Switch, Ucc=7…13V		32-SDIP				-
BA 7740 FS		LIN-IC	=BA 7740S: SMD		24-SMDIP				-
BA 7740 S	Rhm	LIN-IC	VC, HiFi Audio Rec/Play Amp.		22-SDIP				-
BA 7743 FS	Rhm	LIN-IC	VC, HiFi Audio Rec/Play Amp.		24-SMDIP				-
BA 7750 AL	Rhm	LIN-IC	VC, CUE Detection		18-SQP				-
BA 7751 ALS	Rhm	LIN-IC	VC, Audio Signal Processor, Ucc=4,5…12,5V		24-SQP				KA 8401
BA 7752 LS	Rhm	LIN-IC	VC, Audio Signal Processor, Ucc=4,5…12,5V		24-SQP				-
BA 7755 A	Rhm	LIN-IC	VC++, Audio Kopfumsch./Head Switch, Ucc=9(4…13V)		5-SIP				-
BA 7755 AF		LIN-IC	=BA 7755A: SMD		8-MDIP				-
BA 7757 BK	Rhm	LIN-IC	VC, Audio Rec/Play Amp., Switchless, Ucc=4…6V		32-MP				-
BA 7760	Rhm	LIN-IC	Mikrofonverst./Microphone Amp. f. Karaoke		14-DIP				-
BA 7760 F		LIN-IC	=BA 7760: SMD		14-MDIP				-
BA 7765 AS	Rhm	LIN-IC	VC++, Audio Signal Processor, Ucc=8…13V		32-SDIP				-
BA 7766 AS	Rhm	LIN-IC	VC++, Audio Signal Processor, Ucc=8…13V		32-SDIP				-
BA 7767 AS	Rhm	LIN-IC	VC++, Audio Signal Processor, Ucc=8…13V		32-SDIP				-
BA 7792 LS	Rhm	LIN-IC	VC++, Audio Signal Processor, Ucc=7,5…12,5V		24-SPQ				-
BA 7795 LS	Rhm	LIN-IC	VC++, Audio Signal Processor, Ucc=7,5…12,5V		24-SPQ				-
BA 8204	Rhm	LIN-IC	Telecom, Klingelton/Tone Ringer		8-DIP				-
BA 8204 F		LIN-IC	=BA 8204: SMD		8-MDIP				-
BA 8205	Rhm	LIN-IC	Telecom, Klingelton/Tone Ringer		8-DIP				-
BA 8205 F		LIN-IC	=BA 8205: SMD		8-MDIP				-
BA 8206	Rhm	LIN-IC	Telecom, Klingelton/Tone Ringer		8-DIP				-
BA 8206 F		LIN-IC	=BA 8206: SMD		8-MDIP				-
BA 8210 N	Rhm	LIN-IC	Telecom, Sprechkreis/Speech Network		10-SIP				-
BA 8211 N	Rhm	LIN-IC	Telecom, Sprechkreis/Speech Network		10-SIP				-
BA 8215	Rhm	LIN-IC	Telecom, Sprechkreis/Speech Network		14-DIP				-
BA 8215 L		LIN-IC	=BA 8215: Fig. ›		16-SQP				-
BA 8216	Rhm	LIN-IC	Telecom, Sprechkreis/Speech Network		14-DIP				-
BA 8420	Rhm	LIN-IC	VC, Servo, Special Playback(Fine Slow)		22-DIP				-
BA 8500	Rhm	LIN-IC	VC, Capstan Servo		28-DIP				-
BA 9101(B,S)	Rhm	A/D-IC	8-Bit A/D-Converter		22-DIP				-
BA 9101(B,S)F	Rhm	A/D-IC	=BA 9101(B,S): SMD		22-MDIP				-
BA 9201	Rhm	D/A-IC	8 Bit, Input Data Latch, Ucc=5V		18-DIP				-
BA 9201 F		D/A-IC	=BA 9201: SMD		28-MDIP				-
BA 9211	Rhm	D/A-IC	10 Bit, Reference Voltg. Supply, Ucc=5V		22-DIP				-
BA 9211 F		D/A-IC	=BA 9211: SMD		22-MDIP				-
BA 9221	Rhm	D/A-IC	12 Bit, Digital Audio, Servo,++, Ucc=5V		20-DIP				-
BA 9221 F		D/A-IC	=BA 9221: SMD		22-MDIP				-
BA 9700 A	Rhm	LIN-IC	S-Reg, DC-DC Converter, Ucc=3,55…24V, 2,8…470kHz		14-DIP				-
BA 9700 AF		LIN-IC	=BA 9700A: SMD		14-MDIP				-
BA 9701	Rhm	LIN-IC	S-Reg, DC-DC Converter, Ucc=2,5V		8-DIP				-
BA 9701 F		LIN-IC	=BA 9701: SMD		8-MDIP				-
BA 9702 FS	Rhm	LIN-IC	SMD, 3x S-Reg Controller, Ucc=3,6…23V		24-SMDIP				-
BA 9703 K	Rhm	LIN-IC	SMD, 3x S-Reg Controller, Ucc=3,6…18V		32-MP				-
BA 9704 N	Rhm	LIN-IC	DC-DC Converter f. Electr. Tuning Voltage, Mute		10-SIP				-
BA 9705 AK	Rhm	LIN-IC	SMD, 3x S-Reg Controller, Ucc=3,6…18V		32-MP				-
BA 9706 K	Rhm	LIN-IC	SMD, 3x S-Reg Controller, Ucc=3,6…18V		32-MP				-
BA 10324(A)	Rhm	OP-IC	Quad, Serie 124, ±16V, -40…+85°		14-DIP		(LM 324 N)[16]	14-DIP	… 124…, … 224…
BA 10324(A)F		OP-IC	=BA 10324(A): SMD		14-MDIP				… 124…, … 224…
BA 10324 AFV		OP-IC	=BA 10324A: SMD		14-SMDIP				… 124…, … 224…
BA 10339	Rhm	KOP-IC	Quad, Serie 139, ±18V, -40…+85°		14-DIP		(LM 339 N)[16]	14-DIP	… 139…, … 239…
BA 10339 F		KOP-IC	=BA 10339:SMD		14-MDIP				… 139…, … 239…
BA 10339 FV		KOP-IC	=BA 10339:SMD		14-SSMDIP				… 139…, … 239…
BA 10358	Rhm	OP-IC	Dual, Serie 158, ±16V, -40…+85°		8-DIP		(4558/8-D)[16]	8-DIP	… 158…, … 258…, … 1458…, … 1558…
BA 10358 F		OP-IC	=BA 10358: SMD		8-MDIP				… 158…, … 258…, … 1458…, … 1558…
BA 10358 N		OP-IC	=BA 10358:Fig. ›		8-SIP				… 158…, … 258…, … 1458…, … 1558…
BA 10393	Rhm	KOP-IC	Dual, Serie 193, ±18V, -40…+85°		8-DIP				… 193…, … 293…
BA 10393 F		KOP-IC	=BA 10393: SMD		8-MDIP				… 193…, … 293…
BA 10393 N		KOP-IC	=BA 10393:Fig. ›		8-SIP				… 193…, … 293…
BA 12001	Rhm	LIN-IC	7x PNP Darl, 50V, 0,5A, Usat<1,6V(0,1A), hFE>1000		16-DIP				-
BA 12002	Rhm	LIN-IC	7x PNP Darl, 50V, 0,5A, Usat<1,6V(0,1A), hFE>1000		16-DIP				-
BA 12003	Rhm	LIN-IC	7x PNP Darl, 50V, 0,5A, Usat<1,6V(0,1A), hFE>1000		16-DIP				-
BA 12004	Rhm	LIN-IC	7x PNP Darl, 50V, 0,5A, Usat<1,6V(0,1A), hFE>1000		16-DIP				-
BA 13001	Rhm	LIN-IC	6xPNP Darl, Interf. Drv, Ucc=3…8V, 0,5A, hFE>1000		16-DIP				-
BA 13001 F		LIN-IC	=BA 13001: SMD		16-MDIP				-
BA 13002	Rhm	LIN-IC	6x Darl, Interface Drv, Ucc=3…8V, 0,3A, hFE>1000V		16-DIP				-
BA 13002 F		LIN-IC	=BA 13002: SMD		16-MDIP				-
BA 14741	Rhm	OP-IC	Quad, LF, VCO, ±18V, -40…+85°		14-DIP				-
BA 14741 F		OP-IC	=BA 14741: SMD		14-MDIP				-
BA 15218	Rhm	OP-IC	Dual, lo-noise, Serie 158, ±18V, 3V/µs, -20…75°		8-DIP		(4558/8-D)	8-DIP	… 158…, … 258…, … 1458…, … 1558…
BA 15218 F		OP-IC	=BA 15218: SMD		8-MDIP				… 158…, … 258…, … 1458…, … 1558…
BA 15218 N		OP-IC	=BA 15218:Fig. ›		8-SIP				… 158…, … 258…, … 1458…, … 1558…
BA 15532	Rhm	OP-IC	Dual, lo-noise, ±21V, 20MHz, 8V/µs, -20…+75°		8-DIP		NE 5532/8-D	8-DIP	NE 5532
BA 15532 F		OP-IC	=BA 15532: SMD		8-MDIP				-
BA 15532 N		OP-IC	=BA 15532:Fig. ›		8-SIP				-
BA 17805 T	Rhm	Z-IC	Iso, +5V, 1A		17b	SOT-186	7805/IsoTO-220	17b	… 7805… (TO-220 Iso)
BA 17806 T	Rhm	Z-IC	Iso, +6V, 1A		17b	SOT-186	(7806/TO-220)[3]	17b	… 7806… (TO-220 Iso)
BA 17807 T	Rhm	Z-IC	Iso, +7V, 1A		17b	SOT-186			… 7807… (TO-220 Iso)
BA 17808 T	Rhm	Z-IC	Iso, +8V, 1A		17b	SOT-186	(7808/TO-220)[3]	17b	… 7808… (TO-220 Iso)
BA 17809 T	Rhm	Z-IC	Iso, +9V, 1A		17b	SOT-186	(7809/TO-220)[3]	17b	… 7809… (TO-220 Iso)
BA 17810 T	Rhm	Z-IC	Iso, +10V, 1A		17b	SOT-186	(7810/TO-220)[3]	17b	… 7810… (TO-220 Iso)
BA 17812 T	Rhm	Z-IC	Iso, +12V, 1A		17b	SOT-186	7812/IsoTO-220	17b	… 7812… (TO-220 Iso)
BA 17815 T	Rhm	Z-IC	Iso, +15V, 1A		17b	SOT-186	7815/IsoTO-220	17b	… 7815… (TO-220 Iso)
BA 17818 T	Rhm	Z-IC	Iso, +18V, 1A		17b	SOT-186	7818/IsoTO-220	17b	… 7818… (TO-220 Iso)
BA 17820 T	Rhm	Z-IC	Iso, +20V, 1A		17b	SOT-186	(7820/TO-220)[3]	17b	… 7820… (TO-220 Iso)
BA 17824 T	Rhm	Z-IC	Iso, +24V, 1A		17b	SOT-186	7824/IsoTO-220	17b	… 7824… (TO-220 Iso)

Original	Fabric.	Constr.	Info	{Compl. Fig.		JAEGER	Fig.	International
BAL...BAQ								
BAL 74	Phi,Sie,Tho	Si-Di	SMD, S, 50/50V, 0,25/0,25A, Uf<1V(0,1A), <4ns	35c	SOT-23			(BAR 74)[5]
BAL 99	Phi,Sie,++	Si-Di	SMD, S, 70/70V, 0,25/0,25A, Uf<1,3V(0,1A), <6ns	35d	SOT-23			(BAR 99)[5]
BAL 872	Rhm	LIN-IC	VC, Reel Motor Control, LED Drv f. Cue/Review	16-SQP				-
BAL 6309	Rhm	LIN-IC	VC, Spurious V-Pulse Generator	16-SQP				-
BAP		Si-P	=2SB1132-P (SMD-Marking)	39	SOT-89			›2SB1132
BAQ		Si-P	=2SB1132-Q (SMD-Marking)	39	SOT-89			›2SB1132
BAQ 33	Aeg	Si-Di	SMD, Pico-Ampere, 30V, 0,2A, Uf<1V(0,1A), Ir<3nA	72a(3,4mm)	SOD-80			BAQ 133...135
BAQ 34	Aeg	Si-Di	=BAQ 33: 60V	72a(3,4mm)	SOD-80			BAQ 134...135
BAQ 35	Aeg	Si-Di	=BAQ 33: 125V	72a(3,4mm)	SOD-80			BAQ 135
BAQ 133	Aeg	Si-Di	=BAQ 33:	72a(3,5mm)	DO-213			BAQ 33...35
BAQ 134	Aeg	Si-Di	=BAQ 34:	72a(3,5mm)	DO-213			BAQ 34...35
BAQ 135	Aeg	Si-Di	=BAQ 35:	72a(3,5mm)	DO-213			BAQ 35
BAR								
BAR		Si-P	=2SB1132-R (SMD-Marking)	39	SOT-89			›2SB1132
BAR 10	Tho	Si-Di	Schottky, VHF/UHF Dem, 20V, 35mA, Uf<1V(35mA)	31a	DO-35			HSS 101, 1N5712, 1SS108
BAR 11	Tho	Si-Di	Schottky, VHF/UHF Dem, 15V, 20mA, Uf<1V(20mA)	31a	DO-35			HSS 101, 1N5712, 1SS108
BAR 12-....	Sie	PIN-Di	1MHz...3GHz, 100V, 0,5pF(50V), 5Ω(10mA), 2kΩ(10µA)	31a	DO-35			-
BAR 13-....	Sie	PIN-Di	=BAR 12:	71a(4mm)	SOD-23			-
BAR 14-....	Sie	PIN-Di	=BAR 12: SMD, Dual	35t	SOT-23			-
BAR 15-....	Sie	PIN-Di	=BAR 12: SMD, Dual	35f	SOT-23			-
BAR 16-....	Sie	PIN-Di	=BAR 12: SMD, Dual	35n	SOT-23			-
BAR 17-....	Sie	PIN-Di	=BAR 12: SMD	35p	SOT-23			-
BAR 18	Tho	Si-Di	SMD, Schottky, 70V, 30mA, Uf=0,41V(1mA)	35p	SOT-23			1SS348
BAR 19	Tho	Si-Di	Schottky, UHF Mx, 4V, 30mA, UF<0,6V(10mA), <1pF	31a	DO-35			BA 480...481, BAT 19, BAT 29, 1S1925, ++
BAR 28	Tho	Si-Di	Schottky, UHF Mx, 70V, 15mA, Uf<1V(15mA), <2pF(0V)	31a	DO-35			HSS 102, 1N5711
BAR 35	Tho	Si-Di	Schottky, 5V, Uf<0,45V(10mA), <1pF(0V)	31a	DO-35			-
BAR 42	Tho	Si-Di	SMD, Schottky, 30V, 100mA, Uf<0,65V(50mA)	35p	SOT-23			BAT 54, BAT 64
BAR 43	Tho	Si-Di	SMD, Schottky, 30V, 100mA, Uf<0,45V(15mA)	35p	SOT-23			BAT 54, BAT 64
BAR 43 A		Si-Di	=BAR 43: Dual	35n	SOT-23			BAT 54A, BAT 64-06
BAR 43 C		Si-Di	=BAR 43: Dual	35f	SOT-23			BAT 54C, BAT 64-05
BAR 43 S		Si-Di	=BAR 43: Dual	35t	SOT-23			BAT 54S, BAT 64-04
BAR 46	Tho	Si-Di	SMD, Schottky, Uni, 100V, Uf<0,25V(0,1A), 6pF	35p	SOT-23			-
BAR 46 A		Si-Di	=BAR 46: Dual	35n	SOT-23			-
BAR 60	Sie	PIN-Di	SMD, Triple, HF Att, 100V, 0,1A, 0,25pF(50V)	44	SOT-143			-
BAR 61	Sie	PIN-Di	SMD, Triple, HF Att, 100V, 0,1A, 0,25pF(50V)	44	SOT-143			-
BAR 63	Sie	PIN-Di	SMD, Uni, S, 35V, 0,1A, Uf<1,2V(0,1A), 1Ω(10mA)	35p	SOT-23			-
BAR 63-03...07		PIN-Di	Dual, BAR 63-03W: 71a(SOD-323), -04: 35u(SOT-23), -05: 35f(SOT-23), -06: 35n(SOT-23), -07: 44(AAKK)	71,35,44	(SOT-143)			-
BAR 64	Sie	PIN-Di	SMD, Uni, S, 200V, 0,1A, Uf<1,1V(50mA),<3,5Ω(10mA)	35p	SOT-23			-
BAR 64-03...07		PIN-Di	Dual, BAR 64-03W: 71a(SOD-323), -04: 35u(SOT-23), -05: 35f(SOT-23), -06: 35n(SOT-23), -07: 44(AAKK)	71,35,44	(SOT-143)			-
BAR 65-03W	Sie	PIN-Di	SMD, Uni, S, 35V, 0,1A, Uf<1,2V(0,1A), <0,5pF(5V)	71a(1,7mm)	SOD-323			-
BAR 66	Sie	Si-Di	SMD, Dual, Blitzschutz/Lightning Prot., 50V, 0,2A	35u	SOT-23			-
BAR 74	Sie,Tho	Si-Di	=BAL 74:	35p	SOT-23			(BAL 74)[5]
BAR 79	Sie	PIN-Di	60V, Uf=0,84V(0,1A), 5Ω(10mA), 1100Ω(10µA)	31a	DO-35			-
BAR 99	Sie,Tho	Si-Di	=BAL 99:	35q	SOT-23			(BAL 99)[5]
BAR 223-10...-70	Edl	Si-Di	Rr, 1k...7kV, 0,5A...0,075A, Uf<7...<15V(500...75mA)	31a	(6,3x3mmØ)			-
BAS								
BAS 11	Phi	Si-Di	Uni,contr.av., 300V, 0,35/0,9A, Uf<1,1V(0,3A),<1µs	31a	DO-35	BYD 33 M	31a	BYD 11G...M, BYX 57/...
BAS 12	Phi	Si-Di	=BAS 11: 400V	31a	DO-35	BAD 33 M	31a	BYD 11G...M, BYX 57/...
BAS 15	Phi	Si-Di	S, Uni, 50V, 75/225mA, Uf<1,1V(100mA), <4ns	31a	DO-34	1N4148	31a	BA 218, BAX 13, BAX 91, 1N4148, ++
BAS 16	Phi,Sie,++	Si-Di	SMD, S, 75/85V, 0,25A, Uf<1,25V(0,15A), <6ns	35p	SOT-23			BAS 678, (BAL 99, BAR 99)[5]
BAS 16 W		Si-Di	=BAS 16:	35p(2mm)	SOT-323			-
BAS 17	Phi	Si-St	SMD,Stabi, Uf=0,75...0,83V(10mA), 0,87...0,96V(0,1A)	35p	SOT-23			BZX 84/C0V8
BAS 19	Phi,Sie,Tho	Si-Di	SMD, S, 100/120V, 0,2/0,625A, Uf<1,25V(0,2A),<50ns	35p	SOT-23			BAS 20, BAS 21
BAS 20	Phi,Sie,Tho	Si-Di	=BAS 19: 150/200V	35p	SOT-23			BAS 21
BAS 21	Phi,Sie,Tho	Si-Di	=BAS 19: 200/250V	35p	SOT-23			1SS250
BAS 22	Phi	Si-Di	Schottky Di, 4V, ...18GHz	Chip				-
BAS 23	Phi	Si-Di	Schottky Di, 4V, ...18GHz	Chip				-
BAS 24	Phi	Si-Di	Schottky Di, 4V, ...18GHz	Chip				-
BAS 25	Phi	Si-Di	Schottky Di, 4V, ...18GHz	Chip				-
BAS 26-20	Sie	Si-Di	20V, Uf<0,5V(10mA), <5pF(0V)	31a	DO-35			-
BAS 27	Phi	Si-Di	SMD, contr.av., 300V, 0,25/0,6A, Uf1,2V(0,3A),<1µs	35p	SOT-23			-
BAS 28	Phi,Sie	Si-Di	=BAS 16: Dual	44(AAKK)	SOT-143			-
BAS 29	Phi,Tho	Si-Di	SMD, S, 90V, 0,25/0,6A, Uf<1,25(0,4A), <50ns	35p	SOT-23			BAS 19
BAS 31	Phi,Tho	Si-Di	=BAS 29: Dual	35t	SOT-23			-
BAS 32(L)	Phi	Si-Di	SMD, SS, 75V, 0,2/0,45A, Uf<1V(0,1A), <4ns	72a(3,4mm)	SOD-80	1N4148 SMD	72a(3,4mm)	LL 4148
BAS 33	Aeg	Si-Di	Pico-Ampere, 30V, 0,2A, Uf<1V(0,1A), Ir<3nA(Umax)	31a	DO-35			BAS 45, BAY 135
BAS 34	Aeg	Si-Di	=BAS 33: 60V	31a	DO-35			BAS 45, BAY 135
BAS 35	Phi	Si-Di	=BAS 29: Dual	35n	SOT-23			-
BAS 40	Sie	Si-Di	SMD, Schottky, 40V, 0,12A, Uf<1V(40mA)	35p	SOT-23			-
BAS 40-01...03		Si-Di	BAS 40-01: Chip, -02: DO-35, -03: SOD-23					-
BAS 40-04...07		Si-Di	Dual, BAT 40-04: 35t(SOT-23), -05: 35f(SOT-23), -06: 35n(SOT-23), -07: 44(AAKK)(SOT-143)	35...,44...	SOT-23/143			-
BAS 45	Phi	Si-Di	Pico-Ampere, 125V, 225/450mA, Uf<1V(0,2A), Ir<1nA	31a	DO-34			BAY 135
BAS 45 L		Si-Di	=BAS 45: SMD	72a(3,4mm)	SOD-80			-
BAS 46	Phi	Si-Di	Schottky Di, X-Band Dem, 2V, Uf<0,5V(1mA)		SOD-48			-
BAS 55	Phi	Si-Di	SMD, SS, 60V, 0,25/0,6A, Uf<1V(0,2A), <6ns	35p	SOT-23			BAS 16, BAS 678, (BAL 99, BAR 99)[5]
BAS 56	Phi	Si-Di	=BAS 55: Dual	44(AAKK)	SOT-143			-
BAS 70	Phi,Sie,Tho	Si-Di	SMD, Schottky, SS, 70V, 0,07A, Uf<1V(15mA)	35	SOT-23			-
BAS 70-01...03		Si-Di	BAS 70-01: Chip, -02: DO-35, -03: SOD-23					-
BAS 70-01...07		Si-Di	Dual, BAS 70-04: 35t(SOT-23), -05: 35f(SOT-23) -06: 35n(SOT-23), -07: 44(AAKK)(SOT-143)	35..., 44...	SOT-23/143			-
BAS 78 A	Sie	Si-Di	S, Uni, 50V, 1A, Uf<1,6V(1A), 1µs	≈39a°	SOT-223			-
BAS 78 B	Sie	Si-Di	=BAS 78A: 100V	≈39a°	SOT-223			-
BAS 78 C	Sie	Si-Di	=BAS 78A: 200V	≈39a°	SOT-223			-
BAS 78 D	Sie	Si-Di	=BAS 78D: 400V	≈39a°	SOT-223			-
BAS 79 A...D	Sie	Si-Di	=BAS 78A...D: Dual	≈39e°	SOT-223			-
BAS 81	Phi	Si-Di	=BAT 81: SMD	72a(3,4mm)	SOD-80			TMMBAR28, TMM1N5711, TMM1N6263

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BAS 82	Phi	Si-Di	=BAT 82: SMD		72a(3,4mm)	SOD-80			TMMBAR28, TMM1N5711, TMM1N6263
BAS 83	Phi	Si-Di	=BAT 83: SMD		72a(3,4mm)	SOD-80			TMMBAR28, TMM1N5711, TMM1N6263
BAS 85	Phi	Si-Di	SMD, Schottky, 30V, 0,2/0,3A, Uf<0,8V(0,1A), <5ns		72a(3,4mm)	SOD-80			TMMBAT 42…43, TMMBAT 48
BAS 86	Phi	Si-Di	SMD, Schottky, 50V, 0,2/0,5A, Uf<0,9V(0,1A), <4ns		72a(3,4mm)	SOD-80			TMMBAT 49
BAS 116	Sie	Si-Di	SMD, Pico-Ampere, 75/85V, 0,25A, Uf<1,25V(0,15A) Ir<5nA(75V), 0,5<1µs		35p	SOT-23			-
BAS 125	Sie	Si-Di	SMD, Schottky, Clamping, 25V, 0,1A, Uf<0,95V(35mA)		35p	SOT-23			BAR 42…43
BAS 125-04…07		Si-Di	Dual, BAS 125-04: 35T(SOT-23), -05: 35f(SOT-23), -06: 35n(SOT-23), -07: 44(AAKK)(SOT-143)		35…,44…	SOT-23/143			-
BAS 216	Phi	Si-Di	=BAS 16:		71a(2mm)	=SOD-123			-
BAS 678	Phi	Si-Di	SMD, SS, 60/100V, 0,25/0,6A, Uf<1V(0,2A), <6ns		35p	SOT-23			-
BAT									
BAT 10	Phi	Si-Di	Schottky, X-Band Mx, 1…12GHz		31a				-
BAT 11	Phi	Si-Di	Schottky, X-Band Mx, 1…12GHz		Chip				-
BAT 12	Phi	Si-Di	Schottky, X-Band Monitor, 9,4…9,6GHz			SOD-48			-
BAT 13	Aeg	Si-Di	S, 50/60V, 0,2/0,45A, Uf<1V(50mA), <10ns		9a		1N4148	31a	BAW 62, BAX 95, BAY 61, 1N4148, 1N4151,+
BAT 14-....	Sie	Si-Di	Schottky, S-Band Mx, medium barrier		div.				-
BAT 15-....	Sie	Si-Di	Schottky, S-Band Mx, zero bias, low barrier		div.				-
BAT 16-....	Sie	Si-Di	Schottky, low barrier, 40V, 30mA, Uf<0,7V(2mA)		31a	DO-35			-
BAT 17	Phi,Sie,Tho	Si-Di	SMD, Schottky, S, UHF Mx, 4V, 30mA, F<8dB(900MHz)		35p	SOT-23			1SS350
BAT 17-04…07,DS		Si-Di	Dual, BAT17DS: 35t(SOT-23), -04: 35s(SOT-23), -05: 35f(SOT-23), -06: 35n(SOT-23), -07: 44(AAKK)		35…,44…	SOT-23/143 (SOT-143)			-
BAT 18(DK)	Phi,Sie,Tho	Si-Di	SMD, VHF/UHF S, 35V, 0,1A, <1pF(20V)		35p	SOT-23			-
BAT 18-04…06		Si-Di	Dual, BAT 18-04: 35t, -05: 35f, -06: 35n		35…	SOT-23			-
BAT 19	Tho	Si-Di	Schottky, UHF Mx, 10V, 30mA, <1,2pF(0V/1GHz)		31a	DO-35			BAR 10…11, 1N5712, 1SS88, 1SS106
BAT 21	Fer	Si-Di	16 Di Array, 60V, 0,4/0,5A, Uf<1V(0,1A), <20ns		14-DIP	TO-116			-
BAT 22	Fer	Si-Di	=BAT 21: 40V, Uf<1,1V(0,1A)		14-DIP	TO-116			-
BAT 23	Fer	Si-Di	16 Di Array, 60V, 0,3/0,5A, Uf<1V(0,1A), <20ns		14-DIP	TO-116			-
BAT 24	Fer	Si-Di	=BAT 23: 40V, Uf<1,1V(0,1A)		14-DIP	TO-116			-
BAT 25	Fer	Si-Di	16 Di Array, 60V, 0,4/0,5A, Uf<1V(0,1A), <20ns		14-DIP	TO-116			-
BAT 26	Fer	Si-Di	=BAT 25: 40V, Uf<1,1V(0,1A)		14-DIP	TO-116			-
BAT 27	Fer	Si-Di	16 Di Array, 60V, 0,3/0,5A, Uf<1V(0,1A), <20ns		14-DIP	TO-116			-
BAT 28	Fer	Si-Di	=BAT 27: 40V, Uf<1,1V(0,1A)		14-DIP	TO-116			-
BAT 29	Tho	Si-Di	Schottky, SS, UHF Mx, 5V, 30mA, <1pF(0V)		31a	DO-35			BA 480…481, BAR 19, 1SS88, 1SS106
BAT 30	Sie	Si-Di	Schottky, zero bias, …25GHz, 6,5V, 50mA, <0,18pF		Chip				-
BAT 31	Phi	Si-Di	Mikrowellen-Rausch-/µWave Noise Diode, 10Hz…18GHz		Koax	SOD-31			-
BAT 32	Sie	Si-Di	Schottky-Di, zero bias, …18GHz, 6,5V, 50mA, 0,2pF		51a/2Pin	=SOT-173			-
BAT 34	Tho	Si-Di	5V, 0,05A, Uf<0,68V(10mA), <2pF(0,5V)		31a	DO-35			-
BAT 35	Tho	Si-Di	=4x BAT 34		31a	4x DO-35			-
BAT 36	Tho	Si-Di	5V, 0,1A, Uf<0,4V(0,1A), <20pF(5V)		2c	TO-18			-
BAT 37	Tho	Si-Di	=4x BAT 34		2c	2x TO-18			-
BAT 38	Phi	Si-Di	Schottky, …40GHz		Koax	SOD-42			-
BAT 39(A)	Phi	Si-Di	Schottky, 1…18GHz		Koax	SOD-42			-
BAT 40	Phi	Si-Di	Uf<0,5V(7mA)			SOD-49			-
BAT 41	Tho	Si-Di	Schottky, 100V, 0,1A, Uf<0,45V(1mA), <5ns		31a	DO-35			BAT 46
BAT 42	Itt,Tho	Si-Di	Schottky, 30V, 0,2A, Uf<0,65V(50mA), <5ns		31a	DO-35	BAT 42	31a	BAT 48, BAT 85
BAT 43	Itt,Tho	Si-Di	Schottky, 30V, 0,2A, Uf<0,45V(15mA), <5ns		31a	DO-35	BAT 42	31a	BAT 48, BAT 85
BAT 42W…43W		Si-Di	=BAT 42…43: SMD		71a(2,7mm)	SOD-123			-
BAT 45	Tho	Si-Di	Schottky, SS, UHF Mx, 15V, 30mA, <1,1pF(1V)		31a	DO-35			BAR 10…11, 1N5712
BAT 46	Itt,Tho	Si-Di	Schottky, Uni, 100V, 0,15A, Uf<0,25V(0,1A), 5pF		31a	DO-35			BAT 41
BAT 46 W		Si-Di	=BAT 46: SMD		71a(2,7mm)	SOD-123			-
BAT 47	Tho	Si-Di	Schottky, Uni, 20V, 0,35A, Uf<0,4V(10mA), 20pF(0V)		31a	DO-35	BAT 42	31a	BAT 42…43, BAT 85, MBR 030
BAT 48	Tho	Si-Di	Schottky, Uni, 40V, 0,35A, Uf<0,3V(10mA), 20pF(0V)		31a	DO-35			BAT 86, MBR 040
BAT 49	Tho	Si-Di	Schottky, 80V, 0,5A, Uf<0,32V(10mA), 120pF(0V)		31a	DO-35			BYS 21-90, HRP 32, SB 180
BAT 50(R)	Phi	Si-Di	Schottky, 8…12GHz		Koax				-
BAT 51(R)	Phi	Si-Di	Schottky, 12…18GHz		Koax	SOD-49			-
BAT 52(R)	Phi	Si-Di	Schottky, 12…18GHz		Koax	SOD-49			-
BAT 53	Tho	Si-Di	SMD, Schottky, 10V, 10mA, Uf<0,4V(1mA), <1,2pF(0V)		35p	SOT-23			-
BAT 54	Phi	Si-Di	SMD, Schottky, 30V, 0,2A, <1V(0,1A), <5ns		35p	SOT-23			BAT 64
BAT 54 A,C,S		Si-Di	Dual, BAT 54A: 35n, C: 35f, S: 35t		35…	SOT-23			BAT 64-…
BAT 54 …W		Si-Di	=BAT 54…:		35…(2mm)	SOT-323			-
BAT 59	Phi	Si-Di	Schottky, 26…40GHz		Koax	SOD-42			-
BAT 62	Sie	Si-Di	SMD, Dual, Schottky, lo barrier, 40V, 20mA, 0,35pF		44	SOT-143			-
BAT 63	Sie	Si-Di	SMD, Dual, Schottky, 3V, 0,1A, Uf<0,19V(1mA)		44	SOT-143			-
BAT 62W…63W		Si-Di	=BAT 62…63: SMD		71a(1,7mm)	SOD-323			-
BAT 64	Sie	Si-Di	SMD, Schottky, SS, 30V, 0,2A, Uf<1V(0,1A), <5ns		35p	SOT-23			BAT 54
BAT 64-04…07		Si-Di	Dual, BAT 64-04: 35t(SOT-23), -05: 35f(SOT-23), -06: 35n(SOT-23), -07: 44(AAKK)(SOT-143)		35…,44…	SOT-23/143			BAT 54A,C,S
BAT 65	Sie	Si-Di	SMD, Schottky, Clamping, 30V, 0,5A, Uf<0,7V(0,25A)		71a(2,7mm)	SOD-123			-
BAT 66	Sie	Si-Di	Schottky, Clamping, 30V, 2A, Uf<0,6V(1A)		≈39a°	SOT-223			-
BAT 66-04…06		Si-Di	Dual, BAT 66-04: ≈39°b, -05: ≈39°e, -06: ≈39°n		≈39°…	SOT-223			-
BAT 68	Sie	Si-Di	SMD, Schottky, VHF/UHF Mx,S, 8V, 0,13A, <1pF(0V)		35p	SOT-23			-
BAT 68-03…07		Si-Di	Dual, BAT 68-03W: 71a(SOD-323, -04: 35t(SOT-23), -05: 35f(SOT-23), -06: 35n(SOT-23), -07: 44(AAKK)		71,35,44	(SOT-143)			-
BAT 69	Sie	Si-Di	=BAT 66: SMD		71a(2,7mm)	SOD-123			-
BAT 74	Phi	Si-Di	SMD, Dual, Schottky, 30V, 0,2A, Uf<1V(0,1A), <5ns		44(AAKK)	SOT-143			-
BAT 81	Phi	Si-Di	Schottky, SS, 40V, 30/150mA, Uf<1V(15mA), <1ns		31a	DO-34			HSS 100, 1N6263
BAT 82	Phi	Si-Di	=BAT 81: 50V		31a	DO-34			HSS 100, 1N6263
BAT 83	Phi	Si-Di	=BAT 81: 60V		31a	DO-34			HSS 100, 1N6263
BAT 85	Phi	Si-Di	Schottky, SS, 30V, 0,2/0,3A, Uf<0,8V(0,1A), <5ns		31a	DO-34	BAT 42	31a	BAT 42…43
BAT 86	Phi	Si-Di	Schottky, SS, 50V, 0,2/0,25A, Uf<0,9V(0,1A), <4ns		31a	DO-34			BAT 49
BAT 114-099	Sie	Si-Di	SMD, Dual, Schottky, 4V, 90mA, Uf=0,668V(10mA)		44	SOT-143			-
BAT 114-099R		Si-Di	Quad		44	SOT-143			-
BAV									
BAV 10	Phi,Tho,Tix	Si-Di	SS, 60/75V, 0,3/0,6A, Uf<1V(0,2A), <6ns		31a	DO-35	1N4148	31a	BAV 12, BAW 55, BAW 76, BAX 81
BAV 11	Tho	Si-Di	Schottky, L-Band Mx, 4V, 10mA		Koax	SOD-31			-
BAV 12	Tix	Si-Di	S, 90V, 0,35/0,5A, Uf<1V(0,1A), <10ns		31a	DO-35			BAV 14, BAW 25, BAW 26, BAX 81
BAV 13	Tix	Si-Di	S, 50V, 0,4/0,5A, Uf<1,35(0,4A), <10ns		31a	DO-35			BAV 14, BAW 24, BAW 25, BAW 26
BAV 14	Tix	Si-Di	S, Uni, 120V, 0,5A, Uf<1,2V(0,5A), <10ns		31a	DO-35			BAV 15, BAV 16
BAV 15	Tix	Si-Di	S, Uni, 140V, 0,5A, Uf<1,3V(0,5A), <20ns		31a	DO-35			BAV 16
BAV 16	Tix	Si-Di	S, Uni, 150V, 0,5A, Uf<1,3V(0,5A), <15ns		31a	DO-35			-

Original	Fabric.	Constr.	Info {Compl.	Fig.		JAEGER	Fig.	International
BAV 17	Itt,Phi,++	Si-Di	S, Uni, 25V, 0,25/0,625A, Uf<1,25V(0,2A), <50ns	31a	DO-35	BA 159	31a	BA 196...198, BAW 48...50
BAV 18	Itt,Phi,++	Si-Di	=BAV 17: 50/60V	31a	DO-35	BA 159	31a	BA 196...198, BAW 49...50
BAV 19	Itt,Phi,++	Si-Di	=BAV 17: 100/120V	31a	DO-35	BA 159	31a	BA 196...198, BAW 50
BAV 20	Itt,Phi,++	Si-Di	=BAV 17: 150/200V	31a	DO-35	BA 159	31a	BA 197...198, BAW 50
BAV 21	Itt,Phi,++	Si-Di	=BAV 17: 200/250V	31a	DO-35	BA 159	31a	BA 198
BAV 22(R)	Phi	Si-Di	Schottky, ...12GHz	Koax				-
BAV 23	Phi	Si-Di	SMD,Dual, S, 200/250V, 0,2/0,6A, Uf<1V(0,1A),<50ns	44(AAKK)	SOT-143			-
BAV 23 S		Si-Di	=BAV 23:	35t	SOT-23			-
BAV 24	Tix	Si-Di	S, 50V, 0,3/0,5A, Uf<1V(0,2A), 6<8ns	31a	DO-35	1N4148	31a	BAV 10, BAW 54, BAW 55, BAW 76, 1N4150
BAV 25	Tho	Si-Di	Schottky, S-Band Dem, 4V, 10mA, <0,55pF(0V)	Koax	DO-19			-
BAV 26	Tho	Si-Di	Schottky, S-Band Dem, 4V, 10mA, <0,55pF(0V)	Koax	SOD-31			-
BAV 27	Tho	Si-Di	Schottky, C-Band Dem, 4V, 10mA, <0,55pF(0V)	Koax	DO-19			-
BAV 28	Tho	Si-Di	Schottky, C-Band Dem, 4V, 10mA, <0,55pF(0V)	Koax	SOD-31			-
BAV 29	Tho	Si-Di	Schottky, X-Band Dem, 4V, 10mA, <0,55pF(0V)	Koax	DO-19			-
BAV 30	Tho	Si-Di	Schottky, X-Band Dem, 4V, 10mA, <0,55pF(0V)	Koax	SOD-31			-
BAV 31	Tho	Si-Di	Schottky, L-Band Dem, 4V, 10mA, <0,55pF(0V)	Koax	DO-19			-
BAV 32	Tho	Si-Di	Schottky, L-Band Dem, 4V, 10mA, <0,55pF(0V)	Koax	SOD-31			-
BAV 33	Tho	Si-Di	Schottky, S-Band Mx, 4V, 10mA, <0,55pF(0V)	Koax	DO-19			-
BAV 34	Tho	Si-Di	Schottky, S-Band Mx, 4V, 10mA, <0,55pF(0V)	Koax	SOD-31			-
BAV 35	Tho	Si-Di	Schottky, C-Band Mx, 4V, 10mA, <0,55pF(0V)	Koax	DO-19			-
BAV 36	Tho	Si-Di	Schottky, C-Band Mx, 4V, 10mA, <0,55pF(0V)	Koax	SOD-31			-
BAV 37	Tho	Si-Di	Schottky, X-Band Mx, 4V, 10mA, <0,55pF(0V)	Koax	DO-19			-
BAV 38	Tho	Si-Di	Schottky, X-Band Mx, 4V, 10mA, <0,55pF(0V)	Koax	SOD-31			-
BAV 39	Tho	Si-Di	Dual, 40V, 0,1A, Uf<1V(10mA)	2f	TO-18			-
BAV 40	Phi	Si-Di	8-Di Array, 60V, 0,3/0,9A, Uf<1,3V(0,5A), <6ns	14-DIP	TO-116			-
BAV 41	Phi	Si-Di	8-Di Array, 60V, 0,3/0,9A, Uf<1,3V(0,5A), <6ns	14-DIP	TO-116			-
BAV 42	Phi	Si-Di	8-Di Array, 60V, 0,3/0,9A, UF<1,3V(0,5A), <6ns	14-DIP	TO-116			-
BAV 44	Phi,Tho	Si-Di	S, Uni, 65V, 0,75/3,5A, Uf<1,1V(1A), <20ns	31a	SOD-51			1SS172
BAV 45	Phi,Tho,++	Si-Di	Pico-Ampere,20/35V,50/100mA, Uf<1V(10mA),Ir<5pA/5V	2c	TO-18			BAS 33...34
BAV 45 A		Si-Di	=2x BAV 45	5	TO-72			-
BAV 46(D...F)	Phi	Si-Di	Schottky, 1...18GHz	Koax	SOD-48			-
BAV 47	Tix	Si-Di	Pico-Ampere, 45V, 50mA, Uf<1,2V(10mA), Ir<5pA(20V)	5(K-Acase)	TO-72			BAS 33...34
BAV 48	Tix	Si-Di	=BAV 47: Ir<20pA(20V)	5(K-Acase)	TO-72			BAS 33...34
BAV 49	Tix	Si-Di	=BAV 47: 35V, Ir<100pA(20V)	5(K-Acase)	TO-72			BAS 33...34
BAV 50	Sgs	Si-Di	16-Di Array, 50V, 0,17A, Uf<1V(0,1A), <4ns	14-DIP	TO-116			-
BAV 50 D		Si-Di	=BAV 50:	16-DIP				-
BAV 51	Tho	Si-Di	Schottky, F=6,5dB(1030MHz)	Koax	DO-19			-
BAV 53	Tho	Si-Di	Schottky, 25V, 50mA, Uf<0,7V(10mA), <2pF(0V)	2c	TO-18	BAT 42	31a	BAT 42...43, BAT 85
BAV 53 A		Si-Di	=BAT 53:	31a	DO-35	BAT 42	31a	BAT 42...43, BAT 85
BAV 53 B		Si-Di	=BAT 53: <1,5pF(0,5V)	2c	TO-18	BAT 42	31a	BAT 42...43, BAT 85
BAV 54/....	Tho	Si-Di	S, 30...100V, 0,20,5A, Uf<1V(10mA), <4ns	31a	DO-35	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4148, ++
BAV 55	Sgs	Si-Di	S, Uni, 150V, 0,22A, Uf<0,95V(0,1A), 50ns	31a	DO-7			BA 196...198, BAV 20...21, BAY 80, ++
BAV 56	Tho	Si-Di	S, 70V, Uf<1,3V(0,1A), <6ns			1N4148	31a	BAV 10, BAW 55, BAW 62, BAX 95, 1N4148++
BAV 65(A)	Tho	Si-Di	Schottky, 25V, 0,1A, <1pF(0V, F=6,5dB(1030MHz)	31a	DO-35	BAT 42	31a	BAT 42...43, BAT 85
BAV 66	Tho	Si-Di	Schottky, F=7dB(9375MHz)					-
BAV 67	Sie	Si-Di	S, 75/80V, 90/225mA, Uf<2V(0,1A), <6ns	31a	DO-35	1N4148	31a	BA 219, BAW 46...47, 1N4148, ++
BAV 68	Phi	Si-Di	S, Uni, 150/180V, 0,25/0,5A, Uf<1,1V(0,1A), <50ns	31a	DO-35	BA 159	31a	BA 197...198, BAV 20...21, BAW 50
BAV 69	Phi	Si-Di	=BAV 68: 200/240V	31a	DO-35	BA 159	31a	BA 198, BAV 21
BAV 70	Phi,Sie,++	Si-Di	SMD, Dual, 70/70V, 0,25A, Uf<1,3V(0,1A), <6ns	35f	SOT-23			-
BAV 70 W		Si-Di	=BAV 70:	35f(2mm)	SOT-323			-
BAV 71	Phi	Si-Di	Schottky, 26...40GHz	Koax	SOD-42			-
BAV 72	Phi	Si-Di	Schottky, 26...40GHz	Koax	SOD-50			-
BAV 74	Phi,Sie,++	Si-Di	SMD, Dual, 50V, 0,25A, Uf<1V(0,1A), <4ns	35f	SOT-23			BAV 70
BAV 75	Phi	Si-Di	Schottky, 8...12GHz	Koax	SOD-31			-
BAV 76	Tho	Si-Di	Schottky, X-Band, 3V, 50mA, <0,16pF(0V)	Koax	SOD-50			-
BAV 77	Tho	Si-Di	Schottky, X-Band, 3V, 50mA, <0,16pF(0V)	Koax	SOD-50			-
BAV 79	Tho	Si-Di	Schottky, S-Band, 3V, 50mA, <0,5pF(0V)	Koax	DO-19			-
BAV 80	Tho	Si-Di	Schottky, X-Band, 3V, 50mA, <0,45pF(0V)	Koax	SOD-48			-
BAV 81	Tho	Si-Di	Schottky, X-Band, 3V, 50mA, <0,45pF(0V)	Koax	SOD-48			-
BAV 82	Tho	Si-Di	Schottky, X-Band, 3V, 50mA, <0,45pF(0V)	Koax	SOD-48			-
BAV 83	Tho	Si-Di	=2x BAV 82, Matched Pair	Koax	SOD-48			-
BAV 84	Tho	Si-Di	Schottky, L-Band, 25V, 10mA, <1pF(0V)	31a	DO-35			-
BAV 84 A		Si-Di	=BAV 84:	Koax	DO-19			-
BAV 85	Tho	Si-Di	=4x BAV 84 Matched	31a	DO-35			-
BAV 85 A		Si-Di	=BAV 85:	Koax	DO-19			-
BAV 86	Tho	Si-Di	Schottky, X-Band, 3V, 50mA, <0,16pF(0V)	Koax	SOD-50			-
BAV 87	Tho	Si-Di	=2x BAV 86 Matched Pair	Koax	SOD-50			-
BAV 88	Tho	Si-Di	Schottky, X-Band, 3V, 50mA, <0,16pF(0V)	Koax	SOD-50			-
BAV 89	Tho	Si-Di	=2x BAV 88 Matched Pair	Koax	SOD-50			-
BAV 90	Tho	Si-Di	Schottky	31a	DO-35			-
BAV 91	Tho	Si-Di	=2x BAV 90 Matched Pair	31a	DO-35			-
BAV 92	Tho	Si-Di	Schottky, S-Band, 3V, 50mA, <0,5pF(0V)	Koax	DO-19			-
BAV 93	Tho	Si-Di	Schottky, X-Band, 3V, 50mA, <0,45pF(0V)	Koax	SOD-48			-
BAV 94	Tho	Si-Di	=2x BAV 93 Matched Pair	Koax	SOD-48			-
BAV 95 A...D	Phi	Si-Di	Schottky, X-Band-M, 8...12GHz	Koax	SOD-50			-
BAV 97	Phi	Si-Di	Schottky, 1...18GHz	Koax	SOD-50			-
BAV 98	Aeg	Si-Di	UHF Mx, 18V, 0,3...0,6pF(6V)	Chip				-
BAV 99	Phi,Sie,++	Si-Di	SMD, Dual, 70/70V, 0,25A, Uf<1,3V(0,1A), <6ns	35t	SOT-23			-
BAV 99 W		Si-Di	=BAV 99:	35t(2mm)	SOT-323			-
BAV 100	Aeg,Phi	Si-Di	SMD, Uni, 50/60V, 0,25/0,625A, Uf<1V(0,1A), <50ns	72a(3,4mm)	SOD-80			BAV 200...203
BAV 101	Aeg,Phi	Si-Di	=BAV 100: 100/120V	72a(3,4mm)	SOD-80			BAV 201...203
BAV 102	Aeg,Phi	Si-Di	=BAV 100: 150/200V	72a(3,4mm)	SOD-80			BAV 202...203
BAV 103	Aeg,Phi	Si-Di	=BAV 100: 200/250V	72a(3,4mm)	SOD-80			BAV 203
BAV 105	Phi	Si-Di	SMD, SS, 60/60V, 0,3/0,6A, Uf<1V(0,2A), <6ns	72a(3,4mm)	SOD-80			-
BAV 170	Sie	Si-Di	=BAS 116: Dual, 70V	35f	SOT-23			-
BAV 199	Sie	Si-Di	=BAS 116: Dual, 70V	35t	SOT-23			-
BAV 200	Aeg	Si-Di	=BAV 100:	72a(3,5mm)	DO-213			BAV 100...103
BAV 201	Aeg	Si-Di	=BAV 101:	72a(3,5mm)	DO-213			BAV 101...103
BAV 202	Aeg	Si-Di	=BAV 102:	72a(3,5mm)	DO-213			BAV 102...103
BAV 203	Aeg	Si-Di	=BAV 103:	72a(3,5mm)	DO-213			BAV 103

Original	Fabric.	Constr.	Info	{Compl. Fig.		JAEGER	Fig.	International
BAW								
BAW 10	Tix	Si-Di	Uni, 50V, 0,2A, Uf<1,2V(0,2A)	31a	DO-35	BA 159	31a	BA 157...159, BA 187...190, BAY 18...21, ++
BAW 11	Tix	Si-Di	=BAW 10: 100V	31a	DO-35	BA 159	31a	BA 157...159, BA 188...190, BAY 20...21, ++
BAW 12	Tix	Si-Di	=BAW 10: 150V	31a	DO-35	BA 159	31a	BA 157...159, BA 189...190, BAY 20...21, ++
BAW 13	Tix	Si-Di	=BAW 10: 200V	31a	DO-35	BA 159	31a	BA 157...159, BA 190, BAY 20...21, ++
BAW 14	Tix	Si-Di	=BAW 10: 300V	31a	DO-35	BA 159	31a	BA 157...159, BAY 21, BAY 46, ++
BAW 16	Tix	Si-Di	Uni, 150V, 0,2A, Uf<1,2V(0,2A)	31a	DO-35	BA 159	31a	BA 157...159, BA 189...190, BAY 20...21, ++
BAW 17	Tix	Si-Di	Uni, 200V, 0,2A, Uf<1,2V(0,2A)	31a	DO-35	BA 159	31a	BA 157...159, BA 190, BAY 21, ++
BAW 18	Tix	Si-Di	Uni, 150V, 0,2A, Uf<1,2V(0,2A)	31a	DO-35	BA 159	31a	BA 157...159, BA 189...190, BAY 20...21, ++
BAW 19	Sgs	Varistor	VDR/Varistor, 75/150mA, Uf<0,8V(10mA)					-
BAW 21(A,B)	Itt,Phi,Tho	Si-Di	S,contr.av., 70...90V, 0,4/0,8A, Uf<1V(0,2A),<300ns A=70V, B=90V	31a	DO-35	(BA 159)	31a	BYX 57/..., (BA 173, BA 157...159, ++)
BAW 22	Tho	Si-Di	Ring-Demodulator, 50V, 0,1A, Uf<1V(10mA), <4pF	5	TO-72			-
BAW 23	Tho	Si-Di	=BAW 22: 30V	5	TO-72			-
BAW 24	Aeg,Tix	Si-Di	SS, 40/50V, 0,6A, Uf<1,2V(0,2A), <6ns	31a	DO-35	(1N4148)	31a	BAV 14, BAW 25, BAW 26, BAW 27
BAW 25	Aeg,Tix	Si-Di	SS, 40/50V, 0,15/0,6A, Uf<1V(0,2A), <6ns	31a	DO-35	(1N4148)	31a	BAV 14, BAW 26, BAW 27
BAW 26	Aeg,Tix	Si-Di	SS, 60/75V, 0,15/0,6A, Uf<1,2V(0,2A), <6ns	31a	DO-35	(1N4148)	31a	BAW 27
BAW 27	Aeg,Tix	Si-Di	SS, 60/75V, 0,15/0,6A, Uf<1V(0,2A), <6ns	31a	DO-35	(1N4148)	31a	BAW 26
BAW 28	Sgs	Si-Di	SS, 30V, 0,4/0,6A, Uf=0,78...1V(0,1A), <6ns	31a	DO-35			BAV 13, BAV 14
BAW 29	Sgs	Si-Di	Schottky, Uf<1V(10mA)	31a	DO-7			-
BAW 31	Tho	Si-Di	Dual, 50V, 0,1A	5	TO-72			-
BAW 32 A....E	Tho	Si-Di	Uni, 10...200V, 60mA, Uf<1,3V(60mA) A=200V, B=150V, C=100V, D=50V, E=10V	31a	DO-7			BA 147/..., BA 187...190, BAY 17...21, ++
BAW 33	Tix	Si-Di	S, Uni, 70V, 0,225A, Uf<1,3V(0,35A), <25ns	31a	DO-35	1N4148	31a	BAV 19...21, BAY 43, BAW 50, 1N4148, ++
BAW 36	Sgs	Si-Di	SS, Uni, 60V, 0,4/0,6A, Uf<1V(0,1A), <6ns	31a	DO-35			BAV 14, BAW 24...27
BAW 43	Tix	Si-Di	Uni, 125V, 0,3A, Uf<1V(0,2A), 3µs	31a	DO-7	BA 159	31a	BA 157...159, BA 194, BA 199/..., ++
BAW 45	Sgs,Tix	Si-Di	SS, Uni, 16/20V, 0,1/0,2A, Uf<1,15V(10mA), <6ns	31a	DO-7	1N4148	31a	BA 317, BAY 71, BAY 94, 1N4148, ++
BAW 46	Sgs,Tix	Si-Di	SS, Uni, 60/75V, 0,12/0,24A, Uf<1,12V(50mA), <6ns	31a	DO-7	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4148, ++
BAW 47	Sgs,Tix	Si-Di	SS, Uni, 80/100V, 115/225mA, Uf<1,25V(30mA), <6ns	31a	DO-7	1N4148	31a	BA 202, BA 203, BA 219,
BAW 48	Sgs,Tix	Si-Di	Dem, S, Uni, 40/50V, 0,3/0,6A, Uf<1,15V(0,1A),35ns	31a	DO-7	1N4148	31a	BAX 78, BAW 49, BAW 50, 1N4148, ++
BAW 49	Sgs,Tix	Si-Di	S, Uni, 80/100V, 0,35/0,7A, Uf<0,9V(0,1A), <60ns	31a	DO-7	(1N4148)	31a	BAW 50, BAX 12, BAY 72
BAW 50	Sgs,Tix	Si-Di	S, Uni, 160/200V, 0,35/0,7A, Uf<1V(0,1A), <60ns	31a	DO-7			BAW 50
BAW 51	Sgs,Tix	Si-Di	Uni, 65/80V, 0,3/0,6A, Uf<1,15V(0,1A)	31a	DO-7	BA 159	31a	BA 157...159, BA 193...194, BAW 52, ++
BAW 52	Sgs,Tix	Si-Di	Uni, 160/200V, 0,3/0,6A, Uf<0,92V(0,1A)	31a	DO-7	BA 159	31a	BA 157...159, BA 199/..., BAS 11, ++
BAW 53	Sgs,Tix	Si-Di	SS, Uni, 25/30V, 0,225/0,45A, Uf<1,12V(0,1A), <8ns	31a	DO-7	1N4148	31a	BA 204, BA 221, BAY 74, 1N4148, ++
BAW 54	Sgs,Tix	Si-Di	SS, Uni, 40/50V, 0,3/0,6A, Uf<1V(0,1A), <6ns	31a	DO-7	1N4148	31a	BAV 10, BAV 24, BAW 55, BAW 76, 1N4150
BAW 55	Sgs,Tix	Si-Di	SS, Uni, 60/75V, 0,3/0,6A, Uf<1V(0,2A), <6ns	31a	DO-7	1N4148	31a	BAV 10, BAV 12, BAW 76, BAX 81
BAW 56	Phi,Sie,++	Si-Di	SMD, Dual, S, 70V, 0,25A, Uf<1,3V(0,1A), <6ns	35n	SOT-23			BAW 66, BAW 68
BAW 56 G	Sie	Si-Di	=BAW 56:	44(KKAA)	SOT-143			-
BAW 56 GT	Sie	Si-Di	=BAW 56:	44(AAKK)	SOT-143			-
BAW 56 W	Phi	Si-Di	=BAW 56:	35n(2mm)	SOT-323			-
BAW 57	Tix	Si-Di	SMD, Array, 60V, 0,3A, Uf<1,5V(0,5A), <10pF(0V)	14-MDIP	TO-84/85			-
BAW 57 N		Si-Di	=BAW 57:	14-DIP	TO-116			-
BAW 58	Sgs	Si-Di	Min, S, Uni, 80/100V, 80/160mA, Uf<1V(0,1A), <50ns	36b		1N4148	31a	BAV 19...21, BAY 43, BAY 80, 1N4148, ++
BAW 59	Sgs	Si-Di	Min, SS, Uni, 30/40V, 60/120mA, Uf<1V(0,1A), <6ns	36b		1N4148	31a	BA 217...218, BA 317, BAX 87, 1N4148, ++
BAW 60	Sgs	Si-Di	SS, 15V, 50mA, Uf<1,35V(50mA), <0,85ns	31a	DO-7			-
BAW 62	Gen,Phi,Tix	Si-Di	S, 75V, 0,2/0,45A, Uf<1V(0,1A), <4ns	31a	DO-35	1N4148	31a	BAW 76, BAX 95, 1N4148...4149, ++
BAW 63	Fer,Tix	Si-Di	SMD, S, 60V, 0,2/0,5A, Uf<1,2V(0,11A), <4ns	35p(2mm)	SOT-323			(BAS 16)
BAW 63 A		Si-Di	=BAS 63: 30V	35p(2mm)	SOT-323			(BAS 16)
BAW 63 B		Si-Di	=BAS 63: 15V	35p(2mm)	SOT-323			(BAS 16)
BAW 64	Fer,Tix	Si-Di	=BAS 63: Dual	35f(2mm)	SOT-323			(BAV 70)
BAW 65	Fer,Tix	Si-Di	=BAS 63A: Dual	35f(2mm)	SOT-323			(BAV 70)
BAW 66	Fer,Tix	Si-Di	=BAS 63A: Dual	35n(2mm)	SOT-323			(BAW 56)
BAW 67	Fer,Tix	Si-Di	=BAS 63B: Dual	35f(2mm)	SOT-323			(BAV 70)
BAW 68	Fer,Tix	Si-Di	=BAS 63B: Dual	35n(2mm)	SOT-323			(BAW 56)
BAW 69	Aeg	Si-Di	Schottky, X-Band, 6V, 0,12pF(0V), F=7dB(9375MHz)	Chip				-
BAW 70	Aeg	Si-Di	Schottky, X-Band, 6V, 0,12pF(0V), F=6,5dB(9375MHz)	Koax				-
BAW 75	Aeg,Sie,++	Si-Di	SS, 35V, 0,3/0,5A, Uf<1V(30mA), <4ns	31a	DO-35	1N4148	31a	BAW 54...55, BAW 76, 1N4148, 1N4150
BAW 76	Aeg,Sie,++	Si-Di	SS, 75V, 0,3/0,5A, Uf<1V(0,1A), <4ns	31a	DO-35	1N4148	31a	BAV 10, BAW 55, BAX 81, 1N4148
BAW 77	Tix	Si-Di	Uni, 120V, 0,1A, Uf<1,3V(0,1A)	31a	DO-35	BA 159	31a	BA 147/150, BA 157...159, BA 189...190, ++
BAW 78 A	Sie	Si-Di	SMD, Uni, 50V, 1A, Uf<1,6V(1A)	39q	SOT-89			-
BAW 78 B	Sie	Si-Di	=BAW 78A: 100V	39q	SOT-89			-
BAW 78 C	Sie	Si-Di	=BAW 78A: 200V	39q	SOT-89			-
BAW 78 D	Sie	Si-Di	=BAW 78A: 400V	39q	SOT-89			-
BAW 79 A	Sie	Si-Di	=BAW 78A: Dual	39e	SOT-89			-
BAW 79 B	Sie	Si-Di	=BAW 78B: Dual	39e	SOT-89			-
BAW 79 C	Sie	Si-Di	=BAW 78C: Dual	39e	SOT-89			-
BAW 79 D	Sie	Si-Di	=BAW 78D: Dual	39e	SOT-89			-
BAW 84	Tix	Si-Di	S, Uni, 300/350V, 0,25/1A, Uf<1,1V(0,1A), 700ns	31a	DO-35	BA 159	31a	BA 157...159, BY 204/..., BY 208/..., ++
BAW 85	Tix	Si-Di	=BAW 84: 400/450V	31a	DO-35	BA 159	31a	BA 157...159, BY 204/..., BY 208/..., ++
BAW 86	Tix	Si-Di	=BAW 84: 450/500V	31a	DO-35	BA 159	31a	BA 158...159, BY 204/..., BY 208/..., ++
BAW 90	Tho	Si-Di	Uni, 75V, 0,05A, Uf<1V(10mA)	2c	TO-18			-
BAW 91	Tho	Si-Di	=BAW 90: Dual	2	TO-18			-
BAW 92	Tho	Si-Di	=BAW 90: Dual	5	TO-72			-
BAW 93	Tho	Si-Br	=BAW 90: Quad(Br)	5	TO-72			-
BAW 94	Sgs	Si-Di	Dual, SS, 30V, Uf<1V(10mA), <2ns					-
BAW 95 A...D	Phi	Si-Di	Schottky, X-Band-M, F=6,3...7,8dB(9375MHz)	Koax	SOD-47			-
BAW 96	Tho	Si-Di	Schottky, 4V, 10mA	Koax	DO-19			-
BAW 99	Phi,Tho	Si-Di	SMD, Dual, 25V, 0,05/0,1A, Uf<1,1V(50mA), <4ns					-
BAW 100	Sie	Si-Di	=BAW 56:	44(KKAA)	SOT-143			MA 157A
BAW 101	Sie	Si-Di	SMD, Dual, 300V, 0,2/0,5A, Uf<1,3V(0,1A), 1µs	44(AAKK)	SOT-143			-
BAW 156	Sie	Si-Di	=BAS 116: Dual, 70V	35n	SOT-23			-
BAX								
BAX 11	Aeg	Si-Di	UHF Multiplier (=BXY 26)	Koax				-
BAX 12(A)	Phi,Tho,++	Si-Di	Uni,contr.av., 90V, 0,4/0,8A, Uf<1,25V(0,4A),<60ns	31a	DO-35	BYD 33 M	31a	(BA 157...159, BAV 15...16)
BAX 13(A)	Phi,Tho,++	Si-Di	S, Uni, 50V, 75/150mA, Uf<1,53V(75mA), <6ns	31a	DO-35	1N4148	31a	BA 218, BA 318, BAX 91, BAY 38, 1N4148++
BAX 14	Phi,Tho	Si-Di	S, Uni, 20/40V, 0,5/2A, Uf<1,1V(0,3A), <30ns	31a	SOD-17	(BA 159)	31a	BAV 15, BAV 16, BAV 44, 1SS172
BAX 14 A		Si-Di	=BAX 14: Uf<0,95V(0,3A), <300ns	31a	DO-35	BA 159	31a	BA 157...159, BY 204/..., BY 208/..., ++
BAX 15	Phi,Tix	Si-Di	S,Uni, 150/180V, 0,25/0,5A, Uf<1,35V(0,25A),<300ns	31a	SOD-17	BA 159	31a	BA 157...159, BA 173, BY 204/..., ++
BAX 16(A)	Phi,Tho,++	Si-Di	S, Uni, 150V, 0,2/0,3A, Uf<1,9V(0,2A), <120ns	31a	SOD-17	BA 159	31a	BA 157...159, BA 196...198, BAX 17, BAY 80
BAX 17(A)	Phi,Tho,Tix	Si-Di	S, Uni, 200V, 0,2/0,3A, Uf<1,2V(0,2A), <120ns	31a	SOD-17	BA 159	31a	BA 157...159, BA 197...198, BAV 20...21

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BAX 18(A)	Phi,Tix	Si-Di	Uni, 75V, 0,5/2A, Uf<2V(2A), A: Uf<1,4V(2A)		31a	SOD-17	BA 159	31a	BA 157…159, BY 402, BY 295/…, ++
BAX 20	Aeg	Si-Di	S, Uni, 25/35V, 115/225mA, Uf<1V(0,1A), <250ns		31a	DO-35	1N4148	31a	BAX 15…17, BAX 88, 1N4148, ++
BAX 21	Aeg	Si-Di	=BAX 20: 50/75V		31a	DO-35	1N4148	31a	BA 157…159, BAX 15…17, 1N4148, ++
BAX 22	Aeg	Si-Di	=BAX 20: 100/125V		31a	DO-35	BA 159	31a	BA 157…159, BA 173, BAX 15…17, ++
BAX 25	Aeg	Si-Di	Schottky, SS, 30V, 0,05A(ss),Uf<0,8V(15mA), <0,5ns		31a	DO-7			-
BAX 26	Aeg	Si-Di	Schottky, SS, 30V, 0,1A(ss),Uf<0,86V(30mA), <0,5ns		31a	DO-35			-
BAX 27	Aeg	Si-Di	Schottky, SS, 30V, 0,5A(ss),Uf<0,91V(150mA),<0,5ns		31a	DO-35			-
BAX 28	Sie	Si-Di	3-Di Array, 25V, 115/225mA, Uf<1V(30mA), <4ns		5(AAAK)	TO-72			-
BAX 30	Sie	Si-Di	=BAX 28:		5(KKKA)	TO-72			-
BAX 32	Sgs	Si-Di	RadH, 250V, Uf<0,85V(0,1A)		31a	DO-7			-
BAX 33	Sgs	Si-Di	Dual, SS, 20/30V, 115/225mA, Uf<1V(10mA), <2ns		42(AAKK)	(7x11x5mm)			-
BAX 34	Sgs	Si-Di	Dual, SS, 20/30V, 115/225mA, Uf<1V(10mA), <2ns		42(AAKK)	(7x11x5mm)			-
BAX 35	Sgs	Si-Di	Dual, SS, 20/30V, 115/225mA, Uf<1V(10mA), <2ns		42(AAKK)	(7x11x5mm)			-
BAX 36	Sgs	Si-Di	Dual, S, 50/75V, 0,15/0,3A, Uf<1V(50mA), <50ns		42(AAKK)	7x11x5mm)			-
BAX 37	Sgs	Si-Di	Dual, S, 50/75V, 0,15/0,3A, Uf<1V(50mA), <50ns		42(AAKK)	7x11x5mm)			-
BAX 38	Sgs	Si-Di	Dual, S, 50/75V, 0,15/0,3A, Uf<1V(50mA), <50ns		42(AAKK)	(7x11x5mm)			-
BAX 39	Sgs	Si-Di	=BAX 33: 4-Di			12x11x5mm			-
BAX 40	Sgs	Si-Di	=BAX 34: 4-Di			12x11x5mm			-
BAX 41	Sgs	Si-Di	=BAX 35: 4-Di			12x11x5mm			-
BAX 42	Sgs	Si-Di	=BAX 36: 4-Di			12x11x5mm			-
BAX 43	Sgs	Si-Di	=BAX 37: 4-Di			12x11x5mm			-
BAX 44	Sgs	Si-Di	=BAX 38: 4-Di			12x11x5mm			-
BAX 45	Sgs	Si-Di	Dual,Logic Gate, 40/80V, 0,3/1A, Uf<1V(0,1A),<25ns		2r	TO-5			-
BAX 46	Sgs	Si-Di	=BAX 45:		2r	TO-18			-
BAX 47	Sgs	Si-Br	=BAX 45: Quad(Br)		5	TO-12			-
BAX 48	Sgs	Si-Br	=BAX 45: Quad(Br)		5	TO-72			-
BAX 49	Sgs	Si-Di	=BAX 45: 6 Di		TO-100				-
BAX 50	Sgs	Si-Di	=BAX 45: 8 Di		TO-100				-
BAX 51	Sgs	Si-Di	=BAX 45: 16 Di		TO-100				-
BAX 52	Sgs	Si-Br	=BAX 45: Quad(Br)		5	TO-12			-
BAX 53	Sgs	Si-Br	=BAX 45: Quad(Br)		5	TO-72			-
BAX 54	Sgs	Si-Di	=BAX 45: Quad(Ring-Dem)		5	TO-12			-
BAX 55	Sgs	Si-Di	=BAX 45: Quad(Ring-Dem)		5	TO-72			-
BAX 56	Sgs	Si-Di	Dual,Logic Gate, 40/60V, 0,3/1A, Uf<1V(0,1A), <4ns		2f	TO-5			-
BAX 57	Sgs	Si-Di	=BAX 56:		2n	TO-5			-
BAX 58	Sgs	Si-Di	=BAX 56:		2f	TO-72			-
BAX 59	Sgs	Si-Di	=BAX 56:		2n	TO-72			-
BAX 60	Sgs	Si-Di	=BAX 56: 3 Di		5(AAKA)	TO-12			-
BAX 61	Sgs	Si-Di	=BAX 56: 3 Di		5(KKAK)	TO-12			-
BAX 62	Sgs	Si-Di	=BAX 56: 3 Di		5(AAKA)	TO-72			-
BAX 63	Sgs	Si-Di	=BAX 56: 3 Di		5(KKAK)	TO-72			-
BAX 64	Sgs	Si-Di	=BAX 56: 4 Di		TO-99				-
BAX 65	Sgs	Si-Di	=BAX 56: 4 Di		TO-99				-
BAX 66	Sgs	Si-Di	=BAX 56: 5 Di		TO-99				-
BAX 67	Sgs	Si-Di	=BAX 56: 5 Di		TO-99				-
BAX 68	Sgs	Si-Di	=BAX 56: 6 Di		TO-99				-
BAX 69	Sgs	Si-Di	=BAX 56: 6 Di		TO-99				-
BAX 70	Sgs	Si-Di	=BAX 56: 7 Di		TO-99				-
BAX 71	Sgs	Si-Di	=BAX 56: 7 Di		TO-99				-
BAX 72	Sgs	Si-Di	=BAX 56: 8 Di		TO-100				-
BAX 73	Sgs	Si-Di	=BAX 56: 8 Di		TO-100				-
BAX 74	Tix	Si-Di	S, 25/30V, Uf<1V(30mA), <10ns		10		1N4148	31a	BA 317…318, BAY 38, BAY 71, 1N4148, ++
BAX 78	Phi,Tix	Si-Di	S, 55/55V, 0,3/0,6A, Uf<0,95V(0,1A), <20ns		31a	DO-7	1N4148	31a	BA 318, BAY 38, BAY 69, 1N4148, ++
BAX 79	Sgs	Si-Di	S, 50V, 0,4/0,6A, Uf<0,92V(0,1A), <4ns		31a	DO-7	(1N4148)	31a	BAV 13, BAV 14, BAW 24…27
BAX 80	Tix	Si-Di	S, 50V, 0,15A, Uf<1V(10mA), <4ns		31a	DO-35	1N4148	31a	BAX 80, BAW 62, BAY 95, 1N4148, ++
BAX 81	Tix	Si-Di	S, 90/90V, 0,35/0,5A, Uf<1V(0,1A), <6ns		31a	DO-35	(1N4148)	31a	BAV 14
BAX 82	Tix	Si-Di	S, 50/50V, 0,25/0,5A, Uf<1,1V(0,1A), <6ns		31a	DO-35	1N4148	31a	BAV 10, BAW 54…55, BAW 76, 1N4148, ++
BAX 83	Tix	Si-Di	S, 100V, 75mA, Uf<1V(10mA), <10ns		31a	DO-35	1N4148	31a	BA 202…203, BA 219, BAX 96, 1N4148, ++
BAX 84	Tho,Tix	Si-Di	S, 50V, 75mA, Uf<1V(20mA), <6ns		31a	DO-35	1N4148	31a	BA 218, BA 318, BAX 13, BAX 91, 1N4148++
BAX 85	Tho,Tix	Si-Di	=BAX 84: <15ns		31a	DO-35	1N4148	31a	BA 218, BA 318, BAX 13, BAX 91, 1N4148++
BAX 86 A	Tix	Si-Di	S, 50V, 75mA, Uf<1V(10mA), <8ns		31a	DO-35	1N4148	31a	BA 218, BA 318, BAX 13, BAX 91, 1N4148++
BAX 86 B		Si-Di	=BAX 86A: <10ns		31a	DO-35	1N4148	31a	BA 218, BA 318, BAX 13, BAX 91, 1N4148++
BAX 87	Tix	Si-Di	S, 40V, 75mA, Uf<1,15V(10mA), 6ns		31a	DO-35	1N4148	31a	BA 218, BA 318, BAX 13, BAX 91, 1N4148++
BAX 88	Tix	Si-Di	S, 20V, 75mA, Uf<1V(4mA), <150ns		31a	DO-35	1N4148	31a	BAX 15…17, BAY 92, BAW 21, 1N4148, ++
BAX 89 A	Tix	Si-Di	S, 45V, 75mA, Uf<1V(15mA), <10ns		31a	DO-35	1N4148	31a	BA 218, BA 318, BAX 13, BAY 38, 1N4148++
BAX 89 B		Si-Di	=BAX 89A: Uf<1V(20mA), <20ns		31a	DO-35	1N4148	31a	BA 218, BA 318, BAX 13, BAY 38, 1N4148++
BAX 89 C		Si-Di	=BAX 89A: Uf<1V(20mA), 6ns		31a	DO-35	1N4148	31a	BA 218, BA 318, BAX 13, BAY 38, 1N4148++
BAX 90 A	Tix	Si-Di	S, 45V, 75mA, Uf<1V(5mA), <50ns		31a	DO-35	1N4148	31a	BAX 80, BAX 85, BAX 94, 1N4148, ++
BAX 90 B		Si-Di	=BAX 90A: 50V, UF<1V(50mA)		31a	DO-35	1N4148	31a	BAX 80, BAX 85, BAX 94, 1N4148, ++
BAX 90 C		Si-Di	=BAX 90A: <4ns		31a	DO-35	1N4148	31a	BA 218, BA 318, BAX 13, BAX 91, 1N4148++
BAX 91(A…C)	Tix	Si-Di	S, 50V, 75mA, Uf<1V(10mA), <4ns		31a	DO-35	1N4148	31a	BA 218, BA 318, BAX 13, BAX 91, 1N4148++
BAX 92	Tix	Si-Di	S, 50V, 75mA, Uf<1V(50mA), <10ns		31a	DO-35	1N4148	31a	BA 218, BA 318, BAX 13, BAX 91, 1N4148++
BAX 93	Tix	Si-Di	=BAX 92: <6ns		31a	DO-35	1N4148	31a	BA 218, BA 318, BAX 13, BAX 91, 1N4148++
BAX 94	Tix	Si-Di	S, 50V, 75mA, Uf<1V(75mA), <50ns		31a	DO-35	1N4148	31a	BAX 85, BAX 89, BAX 90, 1N4148, ++
BAX 95	Tix	Si-Di	S, 50/75V, 0,2A, Uf<1(0,2A), <4ns		31a	DO-35	1N4148	31a	BAW 62, BAW 76, 1N4148…4149, ++
BAX 96(A…C)	Tix	Si-Di	S, 100V, 75mA, Uf<1V(10mA), <4ns		31a	DO-35	1N4148	31a	BA 219, 1N4148…4149, 1N4151
BAX 157	Idr	Si-Di	Uni, 400V, 0,5/2A, Uf=0,97(0,4A), 400ns		31a	DO-15	BA 159	31a	BY 204/4, BY 206, BY 406, BY 208/600, ++
BAX 158	Idr	Si-Di	=BAX 157: 600V		31a	DO-15	BA 159	31a	BY 204/8, BY 207, BY 407, BY 208/600, ++
BAX 159	Idr	Si-Di	=BAX 157: 1000V		31a	DO-15	BA 159	31a	BY 204/10, BY 208/1000, BY 268, ++
BAY									
BAY 14	Aeg	Si-Di	Uni, 500V, 0,2/0,5A, Uf<1V(0,1A)		34a	DO-13	1N4007	31a	BA 158…159, BAY 89, 1N4005…4007, ++
BAY 15	Aeg	Si-Di	=BAY 14: 650V		34a	DO-13	1N4007	31a	BA 159, BAY 90, 1N4006…4007, ++
BAY 16	Aeg	Si-Di	=BAY 14: 800V		34a	DO-13	1N4007	31a	BA 159, BAY 90, 1N4006…4007
BAY 17	Itt,Tho,Tix	Si-Di	Uni, 15V, 0,25A, Uf<1V(0,1A), 1µs		31a	DO-7	BA 159	31a	BA 157…159, BAY 44…46, BAY 86…89, ++
BAY 18	Itt,Tho,Tix	Si-Di	=BAY 17: 60V		31a	DO-7	BA 159	31a	BA 157…159, BAY 44…46, BAY 86…89, ++
BAY 19	Itt,Tho,Tix	Si-Di	=BAY 17: 120V		31a	DO-7	BA 159	31a	BA 157…159, BAY 45…46, BAY 87…89, ++
BAY 20	Itt,Tho,Tix	Si-Di	=BAY 17: 180V		31a	DO-7	BA 159	31a	BA 157…159, BAY 56, BAY 88…89, ++
BAY 21	Itt,Tho,Tix	Si-Di	=BAY 17: 350V		31a	DO-7	BA 159	31a	BA 157…159, BAY 46, BAY 88…89, ++
BAY 23	Itt,Tho	Si-Di	Uni, 1000V, 80mA		31a	(15x2,7Ø)			BAY 90…91, BY 203/12, 1N5181…5184
BAY 24	Itt,Tho	Si-Di	=BAY 23: 1500V		31a	(15x2,7Ø)			BAY 91, BY 203/16, 1N5181…5184
BAY 25	Itt,Tho	Si-Di	=BAY 23: 2000V		31a	(15x2,7Ø)			BAY 91, BY 203/20, 1N5181…5184
BAY 26	Itt,Tho	Si-Di	=BAY 23: 3000V		31a	(15x2,7Ø)			HVG 3, 1N1733, 1N5181…5184

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BAY 31	Itt,Tix	Si-Di	SS, 15V, 0,1/0,2A, Uf=1V(70mA), 2,3ns		31a	DO-7	1N4148	31a	BA 317…318, BAY 38, BAY 71, 1N4148, ++
BAY 32	Phi,Tix	Si-Di	Uni, 150V, 0,17/0,25A, Uf<1,5V(0,1A), <5µs		31a	DO-7	BA 159	31a	BA 157…159, BA 147/150, BA 189…190, ++
BAY 33	Phi,Tix	Si-Di	Uni, S, 150V, 0,13/0,2A, Uf<2,5V(0,1A), <500ns		31a	DO-7	BA 159	31a	BA 157…159, BAX 15…17, BA 173, ++
BAY 35	Itt	Si-Di	hi-ohm, logarithm. Charact., >20GHz, 80…120pF(0V)		31a	DO-7			-
BAY 36	Tix	Si-Di	SS, 30/30V, 0,1A, Uf<1V(30mA), <10ns		31a	DO-7	1N4148	31a	BA 317…318, BAY 69, BAY 71, 1N4148, ++
BAY 38	Phi,Tho,Tix	Si-Di	SS, 50V, 115/225mA, Uf<1V(50mA), <4ns		31a	DO-7	1N4148	31a	BA 318, BAX 80, BAY 95, 1N4148, ++
BAY 39	Phi,Tix	Si-Di	S, 75V, 0,45/0,75A, Uf<1V(0,5A), <160ns		31a	DO-7			BAV 15, BAV 16, BYX 57/…
BAY 40	Itt(SEL)	Si-Di							-
BAY 41	Sie,Tho,Tix	Si-Di	Uni, S, 40/40V, 0,225/0,3A, Uf<1V(0,2A), <15ns		31a	DO-7	1N4148	31a	BA 204, BAX 82, BAX 95, BAY 61, 1N4148++
BAY 42	Sie,Tho,Tix	Si-Di	=BAY 41: 60/60V		31a	DO-7	1N4148	31a	BAW 62, BAX 95, BAY 61, 1N4148, ++
BAY 43	Sie,Tho,Tix	Si-Di	=BAY 41: 80/80V		31a	DO-7	1N4148	31a	BAV 14, 1N4148, 1N4149, 1N4151, ++
BAY 44	Sie,Tho,Tix	Si-Di	Uni, 50/50V, 0,25A, Uf<1,1V(0,1A), 4,5µs		31a	DO-7	BA 159	31a	BA 157…159, BAY 18…21, BAY 86, ++
BAY 45(DHD)	Sie,Tho,Tix	Si-Di	=BAY 44: 150/150V	{DHD: DO-35	31a	DO-7	BA 159	31a	BA 157…159, BAY 20…21, BAY 88, ++
BAY 46	Sie,Tho,Tix	Si-Di	=BAY 44: 300/300V		31a	DO-7	BA 159	31a	BA 157…159, BAY 21, BAY 88, ++
BAY 52	Itt(SEL)	Si-Di	S, 15V, 0,1/0,2A, Uf=1V(20mA), <15ns		31a	DO-7	1N4148	31a	BA 317…318, BAY 38, BAY 71, 1N4148, ++
BAY 60	Phi,Sie,Tix	Si-Di	SS, 25V, 115/225mA, Uf<1V(30mA), 4ns		31a	DO-7	1N4148	31a	BA 317…318, BAY 38, BAY 71, 1N4148, ++
BAY 61	Sie,Tix	Si-Di	SS, 75V, 0,2/0,5A, Uf<1V(10mA), <4ns		31a	DO-35	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4148, ++
BAY 63	Sie,Tho,Tix	Si-Di	SS, 50V, 0,2/0,3A, UF<1V(0,1A), 4ns		31a	DO-7	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4148, ++
BAY 64	Phi,Tix	Si-Di	3-Di Array, 20V, 0,1A, Uf<1V(50mA)		5	TO-12			-
BAY 66	Phi	Si-Di	UHF P, 100V, 0,4A(ss), 25GHz, 4…6pF(100V)		Koax				-
BAY 67	Aeg,Tho,Tix	C-Di	HF Band-S, 35V, Uf<1V(0,2A), <1,5pF(10V), 4…6Ω		31a	DO-7			BA 243…244, BA 282…284, BA 482…484
BAY 68	Aeg,Tho,Tix	Si-Di	SS, 25/35V, 115/225mA, Uf<1V(0,1A), <10ns		31a	DO-35	1N4148	31a	BA 318, BAY 38, BAY 71, 1N4148, ++
BAY 69	Aeg,Tho,Tix	Si-Di	=BAY 68: 50/60V		31a	DO-35	1N4148	31a	BA 318, BAX 80, BAY 38, 1N4148, ++
BAY 70	Aeg	Si-Di	VHF Tuning,AFC, 30V, 4…6/2,2pF(2/30V), 1,5Ω(100M)		31a	DO-7			BA 182, BA 243, BA 283, BA 483…484
BAY 71(DHD)	Itt,Tho,++	Si-Di	SS, 35/70V, 115/225mA, Uf<0,88V(10mA), <4ns	{BAY 71DHD [Tho]:	31a	DO-7 DO-35	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4148, ++
BAY 72	Fch,Tho,Tix	Si-Di	Uni, S, 100/125V, 375/725mA, Uf<1V(0,1A), <400ns		31a	DO-7,DO-35	BA 159	31a	BA 157…159, BAV 15…16, BAW 50, ++
BAY 73	Fch,Tho,Tix	Si-Di	Uni, S, 100/125V, 0,225/0,45A, Uf<0,94V(0,1A),<3µs		31a	DO-7,DO-35	BA 159	31a	BA 157…159, BAY 20…21, BAY 45…46, ++
BAY 74	Fch,Tho,Tix	Si-Di	SS, 35/50V, 0,2/0,6A, Uf<0,93V(0,1A), <4ns		31a	DO-7,DO-35	1N4148	31a	BAW 62, BAX 95, BAY 95, 1N4148, ++
BAY 77	Aeg	Si-Di	SS, 30V, 0,2/0,6A, Uf<1V(0,1A), 2,3ns		31a	DO-7	1N4148	31a	BAW 62, BAX 95, BAY 95, 1N4148, ++
BAY 78(M)	Aeg,Sgs	Si-Di	2x2 Si-Di, Dem, 50/75V, 0,1/0,2A, Uf<1V(50mA)	{BAY 78M [Sgs]:		(9x11x9mm) TO-77			-
BAY 79	Aeg	Si-Di	UHF Multiplier, 68…150GHz		Koax	SOD-50			-
BAY 80	Aeg,Phi,Tho	Si-Di	Uni, 150V, 0,25/0,625A, Uf<1V(0,1A), <50ns		31a	DO-35	BA 159	31a	BA 157…159, BA 196…198, BAV 20…21, ++
BAY 82	Fch,Sgs	Si-Di	SS, 12/15V, 50/150mA, Uf<0,94V(10mA), <0,75ns		31a	DO-7			FD 700, 1N4244, 1N4376
BAY 83	Sgs	Si-Di							-
BAY 84	Tho	Si-Di	SMD, Dual, 90V, 0,15/0,4A, Uf<1,2V(0,4A), <50ns		35t	SOT-23			BAS 31
BAY 85(S)	Tho	Si-Di	SMD, 300V, 0,15A, Uf<1V(0,1A), <40ns		35p	SOT-23			-
BAY 86	Aeg,Tix	Si-Di	Uni, 50/60V, 0,25/0,8A, Uf<1V(0,1A), <3µs		31a	DO-7	BA 159	31a	BA 157…159, BAY 20…21, BAY 45, ++
BAY 87	Aeg,Tix	Si-Di	=BAY 86: 100/120V		31a	DO-7	BA 159	31a	BA 157…159, BAY 20…21, BAY 45, ++
BAY 88	Aeg,Tix	Si-Di	=BAY 86: 300/350V		31a	DO-7	BA 159	31a	BA 157…159, BAY 21, BAY 46, ++
BAY 89	Aeg,Tix	Si-Di	Uni, 500/600V, 0,25/0,8A, Uf<1V(0,1A), <10µs		31a	DO-7	BA 159	31a	BA 158…159, BY 133, BY 204/6, ++
BAY 90	Aeg	Si-Di	=BAY 89: 800/1000V		31a	DO-7	BA 159	31a	BA 159, BY 133, BY 204/10, BYX 94…95,++
BAY 91	Aeg	Si-Di	=BAY 89: 1500/2000V		31a	DO-7	BY 203/20	31a	BY 203/20, BY 268, DM 516
BAY 91 A		Si-Di	=BAY 89: 1500/1750V		31a	DO-7	BY 203/20	31a	BY 203/20, BY 268, DM 516
BAY 92	Aeg,Tix	Si-Di	Uni, S, 600/650V, 0,1/0,2A, Uf<1V(0,1A), <500ns		31a	DO-7	BA 159	31a	BA 158…159, BY 204/6…/10, BY 405, ++
BAY 93	Aeg,Tix,++	Si-Di	S, 20/35V, 115/225mA, UF<1V(10mA), <15ns		31a	DO-35	1N4148	31a	BA 317…318, BAY 38, BAY 69, 1N4148, ++
BAY 94	Aeg,Mot,Tix	Si-Di	SS, 25/35V, 115/225mA, Uf<1V(30mA), <4ns		31a	DO-35	1N4148	31a	BA 317…318, BAY 38, BAY 69, 1N4148, ++
BAY 95	Aeg,Mot,Tix	Si-Di	SS, 50/75V, 0,2/0,45A, Uf<1V(50mA), <4ns		31a	DO-35	1N4148	31a	BAW 62, BAX 95, BAY 61, 1N4148, ++
BAY 96	Phi	Si-Di	UHF P, 120V, 25GHz, 28…39pF(6V), 0,9Ω(450MHz)		32a	DO-4			-
BAY 97	Sie,Tix	Si-Di	SS, 25V, 0,1A, Uf<1V(30mA), <4ns		31a	(7x4x3mm)	1N4148	31a	BA 317…318, BAY 38, BAY 69, 1N4148, ++
BAY 98	Sie,Tix	Si-Di	Uni, S, 150V, 0,2/0,3A, Uf<1V(0,1A), 50ns		31a	DO-7,DO-35	BA 159	31a	BA 157…159, BAX 16…17, BAY 80
BAY 99	Sie,Tix	Si-Di	Uni, S, 40V, 0,1/0,2A, Uf<1V(50mA), <50ns		31a	DO-7,DO-35	1N4148	31a	BAX 80, BAX 94, BAY 41…43, 1N4148, ++
BAY 135	Aeg	Si-Di	Pico Ampere, 140V, 0,2A, Uf<1V(0,1A), Ir<3nA(140V)		31a	DO-35			BAS 45
BB…BBZ									
BB		Si-Di	=1SV128 (SMD-Marking)		35	SOT-23			›1SV128
BB		Si-Di	=1SV237 (SMD-Marking)		44	SOT-143			›1SV237
BB		Si-P	=2SB1119 (SMD-Marking)		39	SOT-89			›2SB1119
BB		Si-P	=2SB831-B (SMD-Marking)		35	SOT-23			›2SB831
BB		Si-N	=2SD1367-BB (SMD-Marking)		39	SOT-89			›2SD1367
BB(p,s)		Si-P	=BCW 61B (SMD-Marking)		35	SOT-23			›BCW 61B
BB		Si-N	=BCX 54-6 (SMD-Marking)		39	SOT-89			›BCX 54-6
BB 1 A3M…L3N	Nec	Si-N+R	=AB 1A3M…L3N:	{BP1…	40c	(SST)			-
BB 1….10	Inr	Si-Di	Uni, S, 250…1200V, 0,3A, Uf<1,2V(0,3A), 800ns BB1=250,BB2=350,BB4=600,BB6=800,BB8=1000,BB10=1200		31a	DO-14	BA 159	31a	BAY 89…91, BY 203/…, BY 208/…, ++
BB 3	Tho	UJT-P	30/35V, 2A(ss), Iv>1mA, η=0,4…0,62, Rbb=2,5…10kΩ		5a	TO-12			-
BB 4 A	Tho	UJT-P	30/35V, 2A(ss), Iv>1mA,η=0,62…0,78, Rbb=2,5…10kΩ		5a	TO-12			-
BB 4 B		UJT-P	BB 4A: Iv>8mA		5a				-
BB 5 (A,B,C)	Tho	UJT-P	60V, 2A(ss), Iv>8mA, η=0,51…0,75, Rbb=6,2…12kΩ A: η=0,51…0,62, B: η=0,56…0,68, C: η=0,67…0,75		5a	TO-12			-
BB 11 A,B	Tho	UJT-P	15/20V, 2A(ss), Iv>2mA, η=0,5…0,9, Rbb=0,8…3,2kΩ		5a	TO-33			-
BB 12	Tho	UJT-P	30/30V, Iv>4mA, η=0,56…0,75, Rbb=4,7…9,1kΩ		5a	TO-72			-
BB 14	Tho	UJT-P	30/30V, Iv>4mA, η=0,68…0,82, Rbb=4,7…9,1kΩ		5a	TO-72			-
BB 18	Tho	UJT-P	20/10V, 1,5A(ss), Iv>2mA, η=0,56…0,9, Rbb=4…10kΩ		5a	TO-72			-
BB 100	Tho	C-Di	VHF Tuning, 25V, 8…12pF(3V), <2Ω(150MHz)		31a	DO-7			BB 106, BB 205G, BB 405G, BB505G, ++
BB 100 G		C-Di	=BB 100: 35V, 4,4…6,8pF(30V), <2Ω(100MHz)		31a	DO-7			BB 106, BB 205G, BB 405G, BB505G, ++
BB 101	Itt	C-Di	FM Tuning, 20V, 90…130pF(4V)		31a	DO-41			BB 110, BB 203, MV 310, 1SV68, 1SV84
BB 102	Aeg	C-Di	VHF Tuning, 50V, 13,8…20,2pF(2V), <1,3Ω(100MHz)		31a	DO-7			BB 106, BB 205G, BB 405G, BB 505G, ++
BB 103	Sie,Tho	C-Di	FM Tuning, 32V, 27…33/11pF(3/30V), <0,5Ω(100MHz)		31a	DO-7			BB 110, BB 203, MV 310, 1SV68, 1SV84
BB 104	Phi,Sie,++	C-Di	Dual, FM Tuning, 32V, 34…42/14pF(3/30V), <0,4Ω		12e	SOT-33			BB 204, BB 304, MV 104, 1SV55, 1SV109
BB 105 A,B	Phi,Sie,++	C-Di	UHF Tuning, 30V, 2…2,8/17pF(25/1V), 0,6Ω(470MHz)		71a(4mm)	SOD-23			BB 121…122, BB 205A,B, BB 405A,B, ++
BB 105 G	Phi,Sie,++	C-Di	VHF Tuning, 30V,2…2,8/17,5pF(25/1V), 0,9Ω(470MHz)		71a(4mm)	SOD-23			BB 106, BB 205G, BB 405G, BB 505G, ++
BB 106	Phi,Tho	C-Di	VHF Tuning (Euro-Band 1), 30V, 4…5,6/32(25/1V)		71a(4mm)	SOD-23			BB 209, BB 229, BB 309, BB 409
BB 107	Sie	C-Di	Dual, AM Tuning, 28V		12e	SOT-33			BB 212, BB 312
BB 109	Phi,Sie,++	C-Di	FM/VHF Tuning, FCC, OIRT, 28/30V 26…32pF/4,3…6pF(3/25V), <0,5Ω(600MHz)		31a	DO-7			BB 143, MV 109, MV 2101…2115, 1SV50
BB 110(B,G)	Aeg,Phi	C-Di	FM Tuning, 30V, 27…33/11pF(3/30V), 0,3Ω(100MHz) B=29…33pF, G=27…31pF		71a(4mm)	SOD-23			BB 203, MV 310, 1SV68, 1SV84
BB 112	Phi,Sie	C-Di	AM Tuning, 12V, 440…520/17,5…34pF(1/8V), 1,4Ω		7d	TO-92			BB 130, BB 509, MV 1401, 1SV134…135,++
BB 113	Phi,Sie,++	C-Di	3-Di AM Tuning, 32V, 230…280/<13pF(1/30V), <4Ω		5-SIP				BB 313, BB 413, MVAM-1
BB 117	Phi	C-Di	AFC, 20V, 8…11/2,2…4pF(4/15V), <1,2Ω(470MHz)		71a(4mm)	SOD-23			BA 121, BB 417, 1SV89
BB 119	Phi	C-Di	AFC, 15V, 20…25pF(4V), 0,9Ω(200MHz)		31a	DO-35			1SV114, 1SV125, 1SV145…146

Original	Fabric.	Constr.	Info (Compl.	Fig.	JAEGER	Fig.	International
BB 121 A,B	Itt,Tho	C-Di	VHF/UHF Tuning, 30V, 0,6Ω(470MHz) A=2…2,35/11pF(25/3V), B=2,25…2,65/12pF(25/3V)	31a	DO-35		BB 205A,B, BB 405A,B, BB 505B, 1SV148,++
BB 122	Itt,Tho	C-Di	VHF/UHF Tuning, 2,1…2,8/13pF(25/3V), 0,9Ω(300MHz)	31a	DO-35		BB 205A,B, BB 405A,B, BB 505B, 1SV148,++
BB 125	Idr	C-Di	VHF/UHF Tuning, 30V, 2…3/12pF(25/3V)	31a	DO-35		BB 205A,B, BB 405A,B, BB 505B, 1SV148,++
BB 126	Idr	C-Di	VHF/UHF Tuning, 30V, 2…3/11pF(25/3V)	31a	DO-35		BB 205A,B, BB 405A,B, BB 505B, 1SV148,++
BB 130	Phi	C-Di	AM Tuning, 32V, 450…550/12…21pF(1/28V), <2Ω	7d	TO-92		BB 112, BB 509, MV 1401, 1SV134…135,++
BB 131	Phi	C-Di	SMD, TV VHF Tuner, 30V, 8…17/0,7…1pF(0,5/28V)	71a(1,7mm)	SOD-323		-
BB 132	Phi	C-Di	SMD,TV VHF Tuner, 30V, 60…75/2,3…2,75pF(0,5/28V)	71a(1,7mm)	SOD-323		-
BB 133	Phi	C-Di	SMD,TV VHF Tuner, …460MHz, 30V, 42/2,4pF(0,8/28V)	71a(1,7mm)	SOD-323		-
BB 134	Phi	C-Di	SMD, TV UHF Tuner, 30V, 19/1,9pF(0,5/28V)	71a(1,7mm)	SOD-323		-
BB 135	Phi	C-Di	SMD, TV UHF Tuner, 30V, 19/1,9pF(0,5/28V)	71a(1,7mm)	SOD-323		-
BB 139	Fch,Itt,Tho	C-Di	VHF Tuning, FCCOIRT, 30V, 4,3…6/29pF(25/3V), 0,5Ω(300MHz)	31a	DO-35		BB 106, BB 209, BB 229, BB 309, BB 409
BB 141 A,B	Itt,Tho	C-Di	VHF/UHF Tuning, 30V, 0,6Ω(470MHz) A=2…2,35/11pF(25/3V), B=2,25…2,65/13pF(25/3V)	31a	DO-35		BB 121A,B, BB 205A,B, BB 405A,B, BB 505B
BB 142	Itt,Tho	C-Di	VHF/UHF Tuning,30V, 2…3/12pF(25/3V), 0,9Ω(300MHz)	31a	DO-35		BB 205A,B, BB 405A,B, BB 505B, 1SV148,++
BB 143 A,B	Itt	C-Di	FM/VHF Tuning, 30V, <0,7Ω(100MHz) A=5,3…5,9/9pF(25/10V), B=5,9…6,4/9pF(25/10V)	31a	DO-35		BB 109, MV 109, MV 2101…2115, 1SV50
BB 203	Sie	C-Di	=BB 103	31a	DO-35		›BB 103
BB 204	Phi,Sie,++	C-Di	=BB 104:	7e	TO-92		›BB 104
BB 205 A,B,G	Phi,Sie,++	C-Di	=BB 105 A,B,G	71a(4mm)	SOD-23		›BB 105A,B,G
BB 209(G)	Aeg,Phi,Sie	C-Di	VHF Tuning, 30V, 2,6…3/18…24pF(25/3V), 0,85Ω(330MHz) (BB 209G:	71a(4mm)	SOD-23 DO-7		BB 106, BB 229, BB 309, BB 409, ++
BB 212(B)	Phi	C-Di	Dual, AM Tuning, 12V, 500…620/22pF(0,5/8V), <2,5Ω	7e	TO-92		BB 107, BB 312
BB 215	Phi	C-Di	SMD, UHF Tuning, 30V, 1,8…2,2/17pF(28/1V), 0,63Ω	72a(3,4mm)	SOD-80		BB 621…623
BB 219	Phi	C-Di	SMD, VHF Tuning, 30V, 2,8…3,2/>31(28/1V), <0,9Ω	72a(3,4mm)	SOD-80		BB 629, BB 631
BB 221	Itt,Tho	C-Di	=BB 121 A,B	31a	DO-35		›BB 121A,B
BB 222	Itt,Tho	C-Di	=BB 122	31a	DO-35		›BB 122
BB 229	Tho	C-Di	=BB 209:	31a	DO-35		›BB 209
BB 240	Phi	C-Di	SMD, VHF Tuning, Band B, …400MHz 32V, 2,4…2,7pF/>0,5pF(28/0,5V), <1Ω(100MHz)	72a(3,4mm)	SOD-80		-
BB 241	Phi	C-Di	SMD, VHF Tuning, Band A, …160MHz 32V, 2,5…3pF/>63pF(28/0,5V), <2Ω(100MHz)	72a(3,4mm)	SOD-80		-
BB 249	Phi	C-Di	SMD, VHF Tuning, FCC, OIRT 30V, 4…5pF/39…46pF(28/1V), <0,6Ω(200MHz)	72a(3,4mm)	SOD-80		-
BB 304	Aeg,Phi,Sie	C-Di	Dual, AM Tuning, 32V, 42…47,5pF(2V), 0,2Ω(100MHz)	7e	TO-92		BB 104, BB 204, MV 104, 1SV55, 1SV109
BB 305 B	Mot	C-Di	UHF Tuning, 35V, 2…2,3pF(25V), <0,8Ω	71a(4mm)	=SOD-23		BB 205A,B, BB 405A,B, BB 505B, 1SV148,++
BB 305 G	Mot	C-Di	VHF Tuning, 35V, 1,8…2,8pF(25V), <1,2Ω	71a(4mm)	=SOD-23		BB 105G, BB 205G, BB 405G, BB 505G, ++
BB 309	Sie	C-Di	VHF Tuning,30V, 3,7…4,5/56pF(28/1V),<0,7Ω(200MHz)	71a(4mm)	SOD-23		BB 106, BB 209, BB 229, BB 409, ++
BB 312	Sie	C-Di	Dual, AM Tuning, 32V, 485/26pF(1/30V), <2Ω(1MHz)	7e	TO-92		BB 107, BB 212
BB 313	Sie	C-Di	3-Di AM Tuning, 12V, 440…530/22pF(1/8,5V), <2,5Ω	5-SIP			BB 113, BB 413, MVAM-1
BB 314	Sie	C-Di	Dual, FM Tuning, 20V, 44,75/20,3pF(2/8pF)	7e	TO-92		BB 104, BB 204, BB 304, MV 104, 1SV 109
BB 319	Tho	C-Di	VHF Tuning	31a	DO-35		BB 106, BB 209, BB 229, BB 409, ++
BB 329 A,B	Itt	C-Di	VHF Tuning, 32V, 0,85Ω(330MHz) A=2,5…32/38pF(28/1V), B=2,8…3,2/38pF(82/1V)	31a	DO-35		BB 106, BB 209, BB 229, BB 409, ++
BB 404(A…E)	Aeg,Itt	C-Di	SMD, Dual, FM Tuning, 15V, 42…47,5pF(2V), 0,4Ω A=42…43,5, B=43…44,5, C=44…45,5pF(2V), D=45…46,5, E=46…47,5pF(2V)	35f	SOT-23		BB 804, BB 814
BB 405 A,B	Phi,Sie,Tho	C-Di	UHF Tuning, 30V, <0,8Ω(470MHz) A=2,2…2,5/15,5pF(25/1V), B=2…2,3/15,5pF(25/1V)	31a	DO-34		BB 205A,B, BB 505A,B, BB 505B, 1SV148,++
BB 405 G	Phi,Sie,Tho	C-Di	VHF Tuning, 30V, 1,8…2,5/15,5pF(25/1V), <1,2Ω	31a	DO-34		BB 205G, BB 505G, BB 609, 1SV124, ++
BB 406	Tho	C-Di	VHF Tuning, 28V, 4…5,1/25pF(25/3V), <0,6Ω(100MHz)	31a	DO-34		BB 106, BB 209, BB 229, BB 609, ++
BB 409	Sie	C-Di	VHF Tuning,FCC,OIRT, 30V, 4,5…5,6/26…32pF(25/3V)	31a	DO-35		BB 106, BB 209, BB 229, BB 609, ++
BB 413	Sie	C-Di	3-Di AM Tuning,32V, 345…410/90…135pF(1/10V), <2Ω	5-SIP			BB 113, BB 313, MVAM-1
BB 417	Phi	C-Di	VHF/UHF AFC, 20V, 2,2…4/8…11pF(15/4V), <1,2Ω	31a	DO-34		BA 121, BB 117, 1SV89
BB 419	Sie	C-Di	SMD,VHF Tuning, 30V, 26…32/4,3…6pF(3/25V), <0,5Ω	71a(2,7mm)	SOD-123		-
BB 421	Tho	C-Di	UHF Tuning, 30V, 1,8…2,2(25V), <0,6Ω	31a	DO-34		BB 205A,B, BB 405A,B, BB 505B, 1SV148,++
BB 422	Tho	C-Di	VHF Tuning, 30V, 1,8…2,6(25V), <0,9Ω	31a	DO-34		BB 205G, BB 405G, BB 505G, 1SV124, ++
BB 439	Sie	C-Di	=BB 419:	71a(1,7mm)	SOD-323		-
BB 501	Sie	C-Di	VHF/UHF AFC, 30V, 1,9…2,4/9…14pF(25/3V), 0,7Ω	7c	TO-92		BA 121, BB 117, BB 417, 1SV89
BB 502	Sie	C-Di	VHF AFC, 30V, 4,3…6/26…32pF(25/3V)	7c	TO-92		BB 119, 1SV114, 1SV125, 1SV145…146
BB 503	Sie,Tho	C-Di	=BB 501: SMD	35p	SOT-23		-
BB 503 DK	Tho	C-Di	=BB 501: SMD, Dual	35f	SOT-23		-
BB 504	Sie,Tho	C-Di	=BB 502: SMD	35p	SOT-23		-
BB 505 B	Aeg,Sie	C-Di	UHF Tuning, 30V, 2…2,3/17pF(25/1V), <0,8Ω(470MHz)	31a	DO-35		BB 205A,B, BB 405A,B, 1SV110…113,++
BB 505 G	Aeg,Sie	C-Di	VHF Tuning,30V, 1,8…2,5/17pF(25/1V), <1,2Ω(470MHz	31a	DO-35		BB 205G, BB 405G, 1SV97, 1SV124,++
BB 509	Itt	C-Di	AM Tuning, 4,43MHz-AFC, 440…600/20…40pF(1/8,5V)	7c	TO-92		-
BB 510	Itt	C-Di	SMD, Dual, AM Tuning, 12V, 440…600/20…40pF(1/9V)	35g	SOT-23		-
BB 512	Sie	C-Di	SMD, AM Tuning, 12V, 440…520/17…34pF(1/8V), 1,4Ω	71a(2,7mm)	SOD-123		-
BB 515 B,G	Phi,Sie	C-Di	SMD, VHF/UHF Tuning, 1,85…22,5/16…19,5pF(28/1V) B=1,85…2,25/17,7pF(28/1V), G=1,8…2,4pF(28V)	71a(2,7mm)	SOD-123		BB 721
BB 521	Itt	C-Di	=BB 221: verbesserte Linearität/improved charact.	31a	DO-35		›BB 221
BB 523	Itt	C-Di	VHF/UHF Tuning, 32V, 1,9…2,25/20pF(28/1V), <0,8Ω	31a	DO-35		BB 205A,B, BB 405A,B, BB 505B, 1SV148,++
BB 525	Sie	C-Di	SMD, Tuning, 30V, 1,8…2,2/18,5…21,5pF(28/1V)	71a(2,7mm)	SOD-123		-
BB 529	Itt	C-Di	=BB 329: verbesserte Linearität/improved charact.	31a	DO-35		›BB 329
BB 531	Itt	C-Di	VHF Tuning, 32V, 3,15…3,55/50pF(28/1V), <1Ω	31a	DO-35		BB 205G, BB 405G, BB 505G, 1SV124, ++
BB 535	Sie	C-Di	=BB 515:	71a(1,7mm)	SOD-323		1SV214
BB 545	Sie	C-Di	=BB 525:	71a(1,7mm)	SOD-323		-
BB 601	Itt	C-Di	SMD, SATV Tuning, 32V, 0,9…1,2/8…9pF(28/1V)	71a(2,7mm)	SOD-123		1SV186
BB 609 A,B	Aeg,Sie	C-Di	VHF Tuning, OIRT, CATV, 30V, 0,8Ω(100MHz) A=2,6…3/>32,5pF(28/1V), B=2,8…3,2/>33,5pF(28/1V)	31a	DO-35		BB 106, BB 209, BB 229, BB 409, ++
BB 610	Sie	C-Di	VHF Tuning, 30V, 3,35/69pF(28/1V), 1,3Ω	31a	DO-35		BB 205G, BB 405G, BB 505G, 1SV124, ++
BB 619(A,B)	Phi,Sie	C-Di	SMD, VHF Tuning, Extended Band, 30V, 0,6Ω(100MHz) 2,4…2,9/33,5…41pF(28/1V) A=2,5…3/37,5pF(28/1V), B=2,8…3,2/<36pF(28/1V)	71a(2,7mm)	SOD-123		BB 515B,G, BB 723, BB 729…731
BB 620	Phi,Sie	C-Di	SMD, VHF Tuning, Hyperband, 30V, 1,3Ω(100MHz) 2,9…3,4/62…76pF(28/1V)	71a(2,7mm)	SOD-123		-
BB 621	Aeg,Itt	C-Di	=BB 221: SMD	72a(3,4mm)	SOD-80		BB 215, BB 623
BB 622	Aeg,Itt	C-Di	=BB 222: SMD	72a(3,4mm)	SOD-80		BB 215, BB 623
BB 623	Itt	C-Di	SMD, VHF/UHF Tuning, 32V, 2,2/20pF(25/1V), <0,8Ω	72a(3,4mm)	SOD-80		BB 215, BB 621…622
BB 629	Aeg,Itt	C-Di	=BB 329: SMD	72a(3,4mm)	SOD-80		BB 219, BB 631
BB 631	Itt	C-Di	SMD, VHF Tuning, 32V, 3,5/50pF(25/1V), <1Ω(300MHz)	72a(3,4mm)	SOD-80		BB 219, BB 629
BB 639	Sie	C-Di	=BB 619:	71a(1,7mm)	SOD-323		-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BB 640	Sie	C-Di	=BB 620:		71a(1,7mm)	SOD-323			-
BB 709 A,B	Sie,Tho	C-Di	VHF Tuning, 30V, 0,75Ω(100MHz) A=2,5…2,9/>32,5pF(28/1V), B=2,7…3/>33,5pF(28/1V)		71a(4mm)	SOD-23			BB 106, BB 209, BB 229, BB 409, ++
BB 721	Itt	C-Di	SMD, UHF Tuning, 35V, 2,1…2,39/>14pF(25/2V),<0,5Ω		71a(2,7mm)	SOD-123			BB 723
BB 723	Itt	C-Di	=BB 623:		71a(2,7mm)	SOD-123			BB 721
BB 729	Itt	C-Di	SMD, VHF Tuning, 35V, 2,38…2,93/30pF(28/2V),<0,8Ω		71a(2,7mm)	SOD-123			BB 723, BB 730…731
BB 730	Itt	C-Di	SMD, VHF Tuning, 28V, 3,15…3,55/25pF(28/1V)		71a(2,7mm)	SOD-123			BB 723, BB 729, BB 731
BB 731	Itt	C-Di	=BB 631:		71a(2,7mm)	SOD-123			BB 723, BB 729…730
BB 801	Sie	C-Di	SMD, SATV Tuning, 30V, 1/9pF(28/1V)		35a	SOT-23			-
BB 804(-0…-4)	Aeg,Phi,Sie	C-Di	=BB 304: SMD, Dual		35f	SOT-23			BB 404, BB 814
BB 809	Phi,Tho	C-Di	VHF Tuning, OIRT, CATV, 30V, 4…5/39/46pF(28/1V)		31a	DO-34			BB 106, BB 209, BB 229, BB 409, ++
BB 811	Phi,Sie	C-Di	SMD, SATV Tuning, …2GHz, 30V, 1Ω(100MHz) 0,85…1,2/7,8…9,8pF(28/1V)		71a(2,7mm)	SOD-123			1SV186
BB 813	Sie	C-Di	SMD, SATV Tuning, …2,5GHz, 30V, 1,8Ω(470MHz) 0,6…0,9/8,5…10pF(28/1V)		71a(2,7mm)	SOD-123			-
BB 814(-1,-2)	Aeg,Sie	C-Di	SMD, Dual, FM Tuning, 20V, 19…22,7/>43pF(8/2V)		35f	SOT-23			BB 404, BB 804
BB 824	Aeg	C-Di	SMD,Dual, Tuning, 20V, 42,5…45pF(2V), <0,5Ω(2MHz)		35f	SOT-23			-
BB 831	Sie	C-Di	=BB 811:		71a(1,7mm)	SOD-323			1SV245
BB 833	Sie	C-Di	=BB 813:		71a(1,7mm)	SOD-323			1SV245
BB 901	Phi	C-Di	SMD, VHF Tuning, 30V, <1,055pF(28V), <3Ω(100MHz)		35p	SOT-23			-
BB 909 A,B	Phi,Tho	C-Di	VHF Tuning, CATV, 32V, 0,8Ω(100MHz) A=2,6…3/>31pF(28/1V), B=2,8…3,2/>33,5pF(28/1V)		31a	DO-34			BB 106, BB 209, BB 229, BB 409, ++
BB 910	Phi	C-Di	VHF Tuning, Band B, …460MHz, 32V, <1Ω(100MHz) 2,4…2,7/>38pF(28/0,5V)		31a	SOD-68			-
BB 911	Phi	C-Di	SMD,VHF Tuning, Band A, …160MHz, 32V, <2Ω(100MHz) 2,5…3/>63pF(28/0,5V)		31a	SOD-68			-
BBC C 106 B	Bbc	50Hz-Thy	200V, 3,2A, Igt/Ih<0,2/<5mA		17e	TO-220	TIC 106 M	17e	TIC 106, TAG 623, TAG 628, S 4060, MCR72
BBC C 106 B-1	Bbc	50Hz-Thy	200V, 2A, Igt/Ih<0,25/<2mA		13e	TO-202	(TIC 106 M)[4]	17e	C 106, TAG 106, TAG 108, C 108, XO 403
BBC C 106 D	Bbc	50Hz-Thy	400V, 3,2A, Igt/Ih<0,2/<5mA		17e	TO-220	TIC 106 M	17e	TIC 106, TAG 623, TAG 628, S 4060, MCR72
BBC C 106 D-1	Bbc	50Hz-Thy	400V, 2A, Igt/Ih<0,25/<2mA		13e	TO-202	(TIC 106 M)[4]	17e	C 106, TAG 106, TAG 108, C 108, XO 403
BBC C 106 E	Bbc	50Hz-Thy	500V, 3,2A, Igt/Ih<0,2/<5mA		17e	TO-220	TIC 106 M	17e	TIC 106, TAG 623, TAG 628, S 4060, MCR72
BBC C 106 E-1	Bbc	50Hz-Thy	500V, 2A, Igt/Ih<0,25/<2mA		13e	TO-202	(TIC 106 M)[4]	17e	C 106, TAG 106, TAG 108, C 108, XO 403
BBC C 106 F	Bbc	50Hz-Thy	600V, 3,2A, Igt/Ih<0,2/<5mA		17e	TO-220	TIC 106 M	17e	TIC 106, TAG 623, TAG 628, S 4060, MCR72
BBC C 106 F-1	Bbc	50Hz-Thy	600V, 2A, Igt/Ih<0,25/<2mA		13e	TO-202	(TIC 106 M)[4]	17e	C 106, TAG 106, TAG 108, C 108, XO 403
BBU		Si-N	=2SD2114K-U (SMD-Marking)		35	SOT-23			›2SD2114K
BBV		Si-N	=2SD2114K-V (SMD-Marking)		35	SOT-23			›2SD2114K
BBW		Si-N	=2SD2114K-W (SMD-Marking)		35	SOT-23			›2SD2114K
BBY 30	Sie	C-Di	FF/VHF Tuning, 30V, 11/29…31pF(30/3V), <0,5Ω		31a	DO-35			-
BBY 31	Phi,Sie,Tho	C-Di	SMD, VHF/UHF Tuning, 30V, 1,8…2,8/17,5pF(25/1V)		35p	SOT-23			-
BBY 39	Phi	C-Di	SMD, Dual, SATV Tuning, 30V, 1,6…2/17,5pF(28/1V)		35f	SOT-23			-
BBY 40	Phi	C-Di	SMD, VHF Tuning, 30V, 3,8…4,8/39…46pF(28/1V)		35p	SOT-23			-
BBY 42	Phi	C-Di	SMD, VHF Tuning, 32V, 2,4…3/>31pF(28/1V), <1Ω		35f	SOT-23			-
BBY 51	Sie	C-Di	SMD, Dual, Tuning, 7V, 3,1/5,3pF(4/1V)		35f	SOT-23			-
BBY 51-03W	Sie	C-Di	=BBY 51:		71a(1,7mm)	SOD-323			-
BBY 52	Sie	C-Di	SMD, Dual, Tuning, 7V, 1,25/1,75pF(4/1V)		35f	SOT-23			-
BBY 52-03W	Sie	C-Di	=BBY 52:		71a(1,7mm)	SOD-323			-
BBY 62	Phi	C-Di	SMD, Dual, UHF Tuning, 30V, 1,6…2/17,5pF(28/1V)		44(AAKK)	SOT-143			-
BC									
BC		Si-P	=2SB1120 (SMD-Marking)		39	SOT-89			›2SB1120
BC		Si-P	=2SB1188 (SMD-Marking)		39	SOT-89			›2SB1188
BC		Si-P	=2SB831-C (SMD-Marking)		35	SOT-23			›2SB831
BC		Si-N	=2SD1367-BC (SMD-Marking)		39	SOT-89			›2SD1367
BC		Si-N	=BCP 54-10 (SMD-Marking)		≈39°	SOT-223			›BCP 54-10
BC(p,s)		Si-P	=BCW 61C (SMD-Marking)		35	SOT-23			›BCW 61C
BC		Si-N	=BCX 54-10 (SMD-Marking)		39	SOT-89			›BCX 54-10
BC 100	Aeg	Si-N	Vid Out, 350/300V, 0,15A, 0,6W, 10MHz		2a	TO-5	BF 259	2a	BF 259, BF 659, BFR 59, BFS 89, 2N5058
BC 101	Idr	Si-N	40V, 40mA, 0,3W, 30MHz		2a	TO-18L	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BC 107	EUR	Si-N	Uni, 50/45V, 0,1/0,2A, 0,3W, 300MHz	{BC177,BC261	2a	TO-18	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BC 107 P	Tix,Fer	Si-N	=BC 107:		7a, 40e	≈TO-92	›BC 107		›BC 107
BC 108	EUR	Si-N	=BC 107: 30/20V	{BC178,BC262	2a	TO-18	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 108 P	Tix,Fer	Si-N	=BC 108:		7a, 40e	≈TO-92	›BC 108		›BC 108
BC 109	EUR	Si-N	=BC 107: 30/20V, In, F<4dB(1kHz)	{BC179,BC263	2a	TO-18	BC 550	7a	BC 169, BC 184, BC 239, BC 549, 2SC2675+
BC 109 P	Tix,Fer	Si-N	=BC 109:		7a, 40e	≈TO-92	›BC 109		›BC 109
BC 110	Aeg,Sie	Si-N	Uni, 80/80V, 50mA, 0,3W, 100MHz		2a	TO-18	BC 546	7a	BC 546, 2SC1890, 2SC3245(A), 2SD756,++
BC 111	Phi	Si-N	Min, LF, 20/20V, 50mA, 0,03W, >50MHz		2a	≈TO-46	(BC 546)[6]	7a	BC 122…123, BC 146
BC 112	Phi	Si-N	Min, LF, 20/20V, 50mA, 0,05W, 150MHz, F<4dB(1kHz)		36b		(BC 546)[6]	7a	BC 122…123, BC 146
BC 113	Nsc,Sgs	Si-N	Uni, 30/30V, 50mA, 0,2W, 100MHz		8a	TO-106	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 113 A		Si-N	=BC 113: 40/40V		8a	TO-106	BC 546	7a	BC 167, BC 183, BC 237, BC 547, 2SD767++
BC 114	Nsc,Sgs	Si-N	=BC 133: In, F<3dB(1kHz)		8a	TO-106	BC 550	7a	BC 169, BC 184, BC 239, BC 549, 2SC2675+
BC 114 A		Si-N	=BC 113: 40/40V, In, F<3dB(1kHz)		8a	TO-106	BC 550	7a	BC 184, BC 550, 2SC2675, 2SC3378,++
BC 115	Nsc,Sgs	Si-N	LF Drv, 40/30V, 0,2A, 0,3W, 80MHz		8a	TO-105	BC 546	7a	BC 167, BC 183, BC 237, BC 547, 2SC3245+
BC 116(A)	Nsc,Sgs	Si-P	Uni, 45/40V, 0,5A, 0,3W, 200MHz, hFE>40, A: >80		8a	TO-105	BC 327	7a	BC 327, BC 636, BC 160…161, 2SB764,++
BC 117	Sgs	Si-N	LF, 120/120V, 50mA, 0,3W, >60MHz		8a	TO-105	BC 141, BF 259	2a	BF 257, BF 297, 2SC1890A, 2SC2363, ++
BC 118	Nsc,Sgs	Si-N	Uni, 45/45V, 0,2W, >200MHz		8a	TO-106	BC 546	7a	BC 167, BC 183, BC 237, BC 547, 2SD767++
BC 119	Sgs	Si-N	LF Out, 60/30V, 1A, 0,8W, >40MHz	{BC139	2a	TO-39	BC 141	2a	BC 140…141, 2N1990, 2N2102, 2N2405, ++
BC 120	Sgs	Si-N	LF Out, 60/30V, 1A, 0,8W, >40MHz		2a	TO-39	BC 141	2a	BC 140…141, 2N1990, 2N2102, 2N2405, ++
BC 121	Sie	Si-N	Min, LF, In, 5/5V, 75mA, 250MHz, F<5dB(1k)	{BC201	(41c)	(2x1,5x1)	(BC 550)[6]	7a	BC 122…123, BC 146
BC 122	Sie	Si-N	=BC 121: 30/20V	{BC202	(41c)	(2x1,5x1)	(BC 550)[6]	7a	BC 123, BC 146
BC 123	Sie	Si-N	=BC 121: 45/30V	{BC203	(41c)	(2x1,5x1)	(BC 550)[6]	7a	-
BC 125(A,B)	Nsc,Sgs	Si-N	LF Drv, 50…60V, 0,5A, 0,3W, 350MHz BC 125=50/30V, A=50/40V, B=60/30V	{BC126	8a	TO-105	BC 337	7a	BC 337, BC 637, BC 140…141, 2SC2235,++
BC 126(A)	Nsc,Sgs	Si-P	LF Drv, 35…40V, 0,6A, 0,3W, 200MHz BC 126=35/30V, A=40/40V	{BC125	8a	TO-105	BC 327	7a	BC 327, BC 638, BC 160…161, 2SA965,++
BC 127	Sgs	Si-N	Min, LF, In, 25/20V, 0,075W, 30MHz		36f		(BC 550)[6]	7a	BC 122…123
BC 128	Sgs	Si-N	Min, LF, 25/20V, 0,1W, 30MHz		36f		(BC 550)[6]	7a	BC 122…123
BC 129	Aeg	Si-N	Uni, 50/45V, 0,1/0,2A, 0,135W, 300MHz		2a	TO-18	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BC 130	Aeg	Si-N	=BC 129: 30/20V		2a	TO-18	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 131	Aeg	Si-N	=BC 129: 30/20V, In, F<4dB(1kHz)		2a	TO-18	BC 550	7a	BC 169, BC 184, BC 239, BC 549, 2SC2675+
BC 132(A)	Nsc,Sgs	Si-N	LF Inp,Drv, 30…40V, 50mA, 0,4W, >40MHz BC 132=30/25V, A=40/40V		8a	TO-106	BC 546	7a	BC 167, BC 183, BC 237, BC 547, 2SC1890+

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BC 134	Sgs	Si-N	Uni, 45/45V, 0,2W, >400MHz		8a	TO-106	BC 546	7a	BC 167, BC 183, BC 237, BC 547, 2SC1890+
BC 135(A)	Sgs	Si-N	Uni, 45/45V, 0,2W, >200MHz, hFE>60, A: >120(10mA)		8a	TO-106	BC 546	7a	BC 167, BC 183, BC 237, BC 547, 2SD767++
BC 136	Nsc,Sgs	Si-N	LF Drv, 60/40V, 0,5A, 0,3W, >60MHz	{BC137	8a	TO-105	BC 141	2a	BC 337, BC 637, BC 140…141, 2SC2235,++
BC 137	Nsc,Sgs	Si-P	LF Drv, 60/40V, 0,5A, 0,3W, >60MHz	{BC136	8a	TO-105	BC 161	2a	BC 327, BC 638, BC 161, 2SA965,++
BC 138	Sgs	Si-N	LF Drv,Out, 60/30V, 1A, 0,8W, >40MHz		2a	TO-39	BC 141	2a	BC 140…141, 2N2405, 2N3019…3020, ++
BC 139(A)	Sgs	Si-P	LF Drv,Out, 40/40V, 0,5A, 0,7W, 200MHz		2a	TO-39	BC 161	2a	BC 160…161, BC 303…304, 2N2303, ++
			hFE>40, A: hFE=120(100mA)	{BC119,BC144,BC185					
BC 140	EUR	Si-N	LF Drv,Out, 80/40V, 1A, 0,75W, >50MHz, <250/850ns		2a	TO-39	BC 141	2a	BCX 40, 2N3019…3020, 2N4238…4239, ++
BC 141	EUR	Si-N	=BC 140: 100/60V	{BC160…161	2a	TO-39	BC 141	2a	BCX 40, 2N3019…3020, 2N4239, ++
BC 142	Sgs,Tix	Si-N	LF Drv,Out, 80/60V, 1A, 0,8W, 90MHz	{BC143	2a	TO-39	BC 141	2a	BC 140…141, BCX 40, 2N3019…3020, ++
BC 143	Sgs,Tix	Si-P	LF Drv,Out, 60/60V, 1A, 0,7W, 170MHz	{BC142	2a	TO-39	BC 161	2a	BC 161, BC 461, BCX 60, 2N4236, ++
BC 144	Sgs	Si-N	LF Drv,Out, 70V, 1A, 0,7W		2a	TO-39	BC 141	2a	BC 140…141, BCX 40, 2N3019…3020, ++
BC 145	Sgs	Si-N	LF Drv, 120/120V, 0,1A, 0,3W, 80MHz		8a	TO-105	BF 259	2a	BF 257…259, BF 297…299, 2SC1890A, ++
BC 146	Aeg,Phi	Si-N	Min, LF, In, 20/20V, 50mA, 150MHz, F<4dB(1k)	{BC200	7c	SOT-42	(BC 546)[6]	7a	BC 122…123
BC 147	Aeg,Phi,Sie	Si-N	=BC 237:	{BC157	11a	SOT-25	›BC 237		›BC 237
BC 148	Aeg,Phi,Sie	Si-N	=BC 238:	{BC158	11a	SOT-25	›BC 238		›BC 238
BC 149	Aeg,Phi,Sie	Si-N	=BC 239:	{BC159	11a	SOT-25	›BC 239		›BC 239
BC 150	Aei	Si-N	Uni, 18/18V, 0,1A, 0,2W, 160MHz		7c	TO-98	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 151	Aei	Si-N	Uni, 25/25V, 0,1A, 0,2W, 160MHz		7c	TO-98	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 152	Aei	Si-N	Uni, 35/35V, 0,5A, 0,36W, 180MHz		7c	TO-98	BC 639	7c	BC 337, BC 635, BC 637, BC 639, 2SC3377+
BC 153	Nsc,Sgs	Si-P	LF Inp In, 40/40V, 0,1A, 0,2W, 70MHz		8a	TO-106	BC 560	7a	BC 214, BC 415…416, BC 560, 2SA1137,++
BC 154	Nsc,Sgs	Si-P	LF Inp In, 40/40V, 0,1A, 0,2W, 70MHz		8a	TO-106	BC 560	7a	BC 214, BC 415…416, BC 560, 2SA1137,++
BC 155	Aeg	Si-N	Min, LF, 5/5V, 50mA, 0,105W, >50MHz		36c	(TOM-13)	(BC 550)[6]	7a	BC 121…123, BC 146
BC 156	Aeg	Si-N	=BC 155: 0,05W		36c	(TOM-23)	(BC 550)[6]	7a	BC 121…123, BC 146
BC 157	Aeg,Phi,Sie	Si-P	=BC 307:	{BC147	11a	SOT-25	›BC 307		›BC 307
BC 158	Aeg,Phi,Sie	Si-P	=BC 308:	{BC148	11a	SOT-25	›BC 308		›BC 308
BC 159	Aeg,Phi,Sie	Si-P	=BC 309:	{BC149	11a	SOT-25	›BC 309		›BC 309
BC 160	EUR	Si-P	LF Drv,Out, 40/40V, 1A, 0,75W, >50MHz, <500/650ns		2a	TO-39	BC 161	2a	BC 460…461, BCX 60, 2N4234…4236, ++
BC 161	EUR	Si-P	=BC 160: 60V	{BC140…141	2a	TO-39	BC 161	2a	BC 461, BCX 60, 2N4235…4236, ++
BC 167	Aeg,Sie	Si-N	=BC 237:	{BC257	7c	TO-92	›BC 237		›BC 237
BC 168	Aeg,Sie	Si-N	=BC 238:	{BC258	7c	TO-92	›BC 238		›BC 238
BC 169	Aeg,Sie	Si-N	=BC 239:	{BC259	7c	TO-92	›BC 239		›BC 239
BC 170	Itt,Nsc	Si-N	Uni, 20/20V, 0,1A, 0,3W, 100MHz	{BC250	7a	TO-92	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 171	Itt,Nsc	Si-N	Uni, 50/45V, 0,1A, 0,3W, 250MHz	{BC251	7a	TO-92	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BC 172	Itt,Nsc	Si-N	=BC 171: 30/20V	{BC252	7a	TO-92	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 173	Itt,Nsc	Si-N	=BC 171: 30/20V, In	{BC253	7a	TO-92	BC 550	7a	BC 169, BC 184, BC 239, BC 549, 2SC2675+
BC 174	Itt,Phi	Si-N	=BC 171: -/64V	{BC256	7a	TO-92	BC 546	7a	BC 182, BC 190, BC 546, 2SC2240, 2SD767+
BC 174[Mot]	Mot	Si-N	=BC 174: Fig. ›		7e	TO-92			
BC 175	Aei	Si-N	LF Drv, 35/35V, 0,5A, 0,56W, 180MHz		7c	TO-92°	BC 639	7c	BC 337…338, BC 635, 2SD1225, 2SD1616,++
BC 177	EUR	Si-P	Uni, 50/45V, 0,1/0,2A, 0,3W, 130MHz	{BC107	2a	TO-18	BC 556	7a	BC 212, BC 257, BC 307, BC 557, 2SB725++
BC 177 P	Tix,Fer	Si-P	=BC 177:		7a, 40e	=TO-92	›BC 177		›BC 177
BC 178	EUR	Si-P	=BC 177: 30/25V	{BC108	2a	TO-18	BC 556	7a	BC 213, BC 258, BC 308, BC 558, 2SB725++
BC 178 P	Tix,Fer	Si-P	=BC 178:		7a, 40e	=TO-92	›BC 178		›BC 178
BC 179	EUR	Si-P	=BC 177: 25/20V, In, F<4dB(1kHz)	{BC109	2a	TO-18	BC 560	7a	BC 214, BC 259, BC 309, BC 559, 2SA1137+
BC 179 P	Tix,Fer	Si-P	=BC 179:		7a, 40e	=TO-92	›BC 179		›BC 179
BC 180	Aei	Si-N	LF Drv, 45/45V, 0,5A, 0,36W, 180MHz		7c	TO-98	BC 639	7c	BC 337, BC 635, 2SD1226, 2SD1616,++
BC 181(A)	Tix	Si-P	Uni, 40/25V, 0,2A, 0,3W, hFE>60, A: hFE>100(50mA)		7a	SOT-30	BC 556	7a	BC 213, BC 257, BC 307, BC 557, 2SB725++
BC 182	EUR	Si-N	=BC 183: 60/50V	{BC212	7a	SOT-30	BC 546	7a	BC 174, BC 190, BC 546, 2SC2240, 2SD767+
BC 182 K	Nsc	Si-N	=BC 182:		8a	TO-106	›BC 182		›BC 182
BC 182 L	Nsc,Tix	Si-N	=BC 182:		7c	TO-92	›BC 182		›BC 182
BC 182 P	Fer	Si-N	=BC 182:		40e	=TO-92	›BC 182		›BC 182
BC 183	EUR	Si-N	Uni, 45/30V, 0,2A, 0,3W, 280MHz	{BC213	7a	SOT-30	BC 546	7a	BC 167, BC 237, BC 547, 2SC2675, 2SD767+
BC 183 K	Nsc	Si-N	=BC 183:		8a	TO-106	›BC 183		›BC 183
BC 183 L	Nsc,Tix	Si-N	=BC 183:		7c	TO-92	›BC 183		›BC 183
BC 183 P	Fer	Si-N	=BC 183:		40e	=TO-92	›BC 183		›BC 183
BC 184	EUR	Si-N	=BC 183: In, F<4dB(1kHz)	{BC214	7a	SOT-30	BC 550	7a	BC 413…414, BC 550, 2SC2240, 2SC2675,++
BC 184 K	Nsc	Si-N	=BC 184:		8a	TO-106	›BC 184		›BC 184
BC 184 L	Nsc,Tix	Si-N	=BC 184:		7c	TO-92	›BC 184		›BC 184
BC 184 P	Fer	Si-N	=BC 184:		40e	=TO-92	›BC 184		›BC 184
BC 185	Sgs	Si-N	LF Drv, 60/30V, 1A, 0,8W, 300MHz	{BC139	2a	TO-39	BC 141	2a	BC 140…141, BCX 40, 2N3019…3020, ++
BC 186	Phi	Si-P	Uni, 40V, 0,1A, 0,3W, >50MHz		2a	TO-18	BC 556	7a	BC 213, BC 257, BC 307, BC 557, 2SB725++
BC 187	Phi	Si-P	=BC 186: 30/25V		2a	TO-18	BC 556	7a	BC 213, BC 258, BC 308, BC 558, 2SB725++
BC 190	Itt	Si-N	Uni, 70/64V, 0,1/0,2A, 0,3W, 250MHz	{BC256	2a	TO-18	BC 546	7a	BC 174, BC 546, 2SC2674…75, 2SC3378,++
BC 192	Itt	Si-P	LF,S, 25V, 0,5A, 0,4W, >100MHz		2a	TO-18	BC 327	7a	BC 327…328, BC 636, 2SA1515, 2SB909,++
BC 194	Aeg	Si-N	Min, LF, 40/25V, 0,8/1A, >250MHz, 25/150ns		36c	(TOM-13)	(BC 337)[6]	7a	(BC 337, BC 635, 2SC3377, 2SD1225,++)[6]
BC 196	Aeg	Si-P	Min, LF, 30/25V, 0,1/0,2A, 150MHz	{BC198	36c	(TOM-23)	(BC 556)[6]	7a	BC 200, BC 202…203
BC 197	Aeg	Si-N	=BC 198: 50/45V		36c	(TOM-23)	(BC 546)[6]	7a	BC 123
BC 198	Aeg	Si-N	Min, LF, 30/20V, 0,1/0,2A, 0,05W, 300MHz	{BC196	36c	(TOM-23)	(BC 546)[6]	7a	BC 122…123, BC 146
BC 199	Aeg	Si-N	=BC 198: In, F<4dB(1kHz)		36c	(TOM-23)	(BC 550)[6]	7a	BC 122…123, BC 146
BC 200	Aeg,Phi	Si-P	Min, LF, In, 20/20V, 50mA, 90MHz, F<4dB(1k)	{BC146	7c	SOT-42	(BC 560)[6]	7a	BC 202…203
BC 201	Sie	Si-P	Min, LF, In, 5/5V, 75mA, 80MHz, F<10dB(1k)	{BC121	(41c)	(2x1,5x1)	(BC 560)[6]	7a	BC 200
BC 202	Sie	Si-P	=BC 201: 30/20V	{BC122	(41c)	(2x1,5x1)	(BC 560)[6]	7a	-
BC 203	Sie	Si-P	=BC 201: 45/30V	{BC123	(41c)	(2x1,5x1)	(BC 560)[6]	7a	-
BC 204	Fch,Tho	Si-P	=BC 205: 50/45V	{BC207	8a	TO-106	BC 556	7a	BC 212, BC 257, BC 307, BC 557, 2SB725++
BC 205	Fch,Tho	Si-P	Uni, 25/20V, 0,1/0,2A, 0,2W, 200MHz	{BC208	8a	TO-106	BC 556	7a	BC 213, BC 258, BC 308, BC 558, 2SB725++
BC 206	Fch,Tho	Si-P	=BC 205: In, F<4dB(1kHz)	{BC209	8a	TO-106	BC 560	7a	BC 214, BC 259, BC 309, BC 559, 2SA1137+
BC 207	Fch,Tho	Si-N	=BC 208: 50/45V	{BC204	8a	TO-106	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BC 208	Fch,Tho	Si-N	Uni, 25/20V, 0,1/0,2A, 0,2W, 300MHz	{BC205	8a	TO-106	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 209	Fch,Tho	Si-N	=BC 208: In, F<4dB(1kHz)	{BC206	8a	TO-106	BC 550	7a	BC 169, BC 184, BC 239, BC 549, 2SC2675+
BC 210	Tho	Si-N	LF Drv, 50/25V, 0,7A, 0,45W, >100MHz	{BC215	2a	TO-18	BC 337	7a	BC 337, BC 637, 2SC4485, 2SD1616,++
BC 211	Tho	Si-N	LF, S, 80/40V, 1A, 0,8W, 300MHz, <250/-ns	{BC313	2a	TO-39	BC 141	2a	BC 140…141, BCX 40, 2N3019…3020, ++
BC 211 A		Si-N	=BC 211: 100/60V		2a	TO-39	BC 141	2a	BC 141, BCX 40, 2N3019…3020, ++
BC 212	EUR	Si-P	=BC 213: 60/50V	{BC182	7a	SOT-30	BC 556	7a	BC 256, BC 266, BC 556, 2SA970, 2SB725++
BC 212 K	Nsc	Si-P	=BC 212:		8a	TO-106	›BC 212		›BC 212
BC 212 L	Nsc,Tix	Si-P	=BC 212:		7c	TO-92	›BC 212		›BC 212
BC 212 P	Fer	Si-P	=BC 212:		40e	=TO-92	›BC 212		›BC 212
BC 213	EUR	Si-P	Uni, 45/30V, 0,2A, 0,3W, 350MHz	{BC183	7a	SOT-30	BC 556	7a	BC 257, BC 307, BC 557, 2SA1137, 2SB725+
BC 213 K	Nsc	Si-P	=BC 213:		8a	TO-106	›BC 213		›BC 213
BC 213 L	Nsc,Tix	Si-P	=BC 213:		7c	TO-92	›BC 213		›BC 213
BC 213 P	Fer	Si-P	=BC 213:		40e	=TO-92	›BC 213		›BC 213
BC 214	EUR	Si-P	=BC 213: In, F<2dB(1kHz)	{BC184	7a	SOT-30	BC 560	7a	BC 415…416, BC 560, 2SA970, 2SA1137,++
BC 214 K	Nsc	Si-P	=BC 214:		8a	TO-106	›BC 214		›BC 214
BC 214 L	Nsc,Tix	Si-P	=BC 214:		7c	TO-92	›BC 214		›BC 214

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BC 214 P	Fer	Si-P	=BC 214:		40e	=TO-92	›BC 214		›BC 214
BC 215	Tho	Si-P	LF Drv, 50/30V, 0,6A, 0,4W, 200MHz	{BC210	2a	TO-18	BC 327	7a	BC 327, BC 638, 2SA1705, 2SB1116,++
BC 216(A) [Riz]	Riz	Si-P	LF Drv, 30/20(A=40/30)V, 0,6A, 0,3W, 200MHz		2a	TO-18	BC 327	7a	BC 327, BC 636, 2SA1515, 2SB909,++
BC 216(A,B) [SGS]	Sgs	Si-N	LF, 45/45V, 20mA, 0,85W, 70MHz		2a	TO-18	BC 546	7a	BC 167, BC 183, BC 237, BC 547, 2SC2675+
BC 218(A)	Riz	Si-N	Uni, 30/30(A=45/45)V, 0,1A, 0,3W, 350MHz		2a	TO-18	BC 546	7a	BC 167, BC 183, BC 237, BC 547, 2SD767++
BC 219	Riz	Si-N	LF Drv, 60/30V, 0,5/1A, 0,8W, 40MHz		2a	TO-39	BC 141	2a	BC 140…141, BCX 40, 2N3019…3020, ++
BC 220	Sgs	Si-N	Uni, 30/25V, 50mA, 0,2W, 80MHz		8a	TO-106	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SC2675+
BC 221	Sgs	Si-P	LF Drv, 30/30V, 0,5A, 0,3W, 150MHz	{BC222	8a	TO-105	BC 327	7a	BC 327…328, BC 636, 2SA1515, 2SB909,++
BC 222	Sgs	Si-N	LF Drv, 30/30V, 0,5A, 0,3W, 250MHz	{BC221	8a	TO-105	BC 337	7a	BC 337…338, BC 635, 2SC3377, 2SD1225,++
BC 223	Tix	Si-N	LF Drv, 50/30V, 0,4A, 0,36W		7a	SOT-30	BC 337	7a	BC337, BC 637, BC 639, 2SC4485, 2SD1616+
BC 224	Tix	Si-P	Uni, 30/30V, 30mA, 0,25W		7c	TO-92	BC 556	7a	BC 213, BC 258, BC 308, BC 558, 2SA1039+
BC 225	Sgs	Si-P	LF, In, 40/40V, 0,1A, 0,2W, 70MHz, F=1dB(1kHz)		8a	TO-106	BC 560	7a	BC415…416, BC560, 2SA970, 2SA1136…37++
BC 226 [SGS]	Sgs	Si-N	LF Drv, 40/30V, 0,1A, 0,8W, 40MHz		2a	TO-39	BC 141	2a	BC 140…141, BC 337, BC 635, BC 637, ++
BC 226(A) [Riz]	Riz	Si-P	LF Drv, 30/20(A=40/30)V, 0,6A, 0,3W, 200MHz		2a	TO-18	BC 327	7a	BC 327…328, BC 636, 2SA1515, 2SB909,++
BC 231	Tix	Si-P	LF Drv, 40/30V, 0,4A, 0,625W, 250MHz	{BC232	7c	TO-92	BC 640	7c	BC 327, BC 636, 2SA1515, 2SB909,++
BC 231 M		Si-P	=BC 231: 0,8W		2a	TO-39	BC 161	2a	BC 160…161, BCX 60, 2N2303, 2SA606,++
BC 232	Tix	Si-N	LF Drv, 40/30V, 0,4A, 0,625W, 300MHz	{BC231	7c	TO-92	BC 639	7c	BC 337, BC 635, 2SC3377, 2SD1225,++
BC 232 M		Si-N	=BC 232: 0,8W		2a	TO-39	BC 141	2a	BC 140…141, BCX 40, 2N3053, 2SC2108,++
BC 234(A)	Riz	Si-N	Uni, 30/30(A=45/45)V, 0,1A, 0,3W, 350MHz		2a	TO-18	BC 546	7a	BC 167, BC 183, BC 237, BC 547, 2SC3378+
BC 235(A)	Riz	Si-N	Uni, 30/30(A=45/45)V, 0,1A, 0,3W, 350MHz		2a	TO-18	BC 546	7a	BC 167, BC 183, BC 237, BC 547, 2SC3378+
BC 236	Tho	Si-N	Nixie, 120/120V, 50mA, 0,3W		8a	TO-106	BF 420 A	7c	BF 297…299, BF 422, BSS 38, BSX 21, ++
BC 237	EUR	Si-N	=BC 238: 50/45V	{BC307	7a	TO-92	BC 546	7a	BC 167, BC 182, BC 547, 2SC2240, 2SD767+
BC 237 P	Fer	Si-N	=BC 237:		40e	=TO-92	›BC 237		›BC 237
BC 238	EUR	Si-N	Uni, 30/20V, 0,1/0,2A, 0,3W, 250MHz	{BC308	7a	TO-92	BC 546	7a	BC 168, BC 183, BC 548, 2SC2240, 2SD767+
BC 238 P	Fer	Si-N	=BC 238:		40e	=TO-92	›BC 238		›BC 238
BC 239	EUR	Si-N	=BC 238: In, F<4dB(1kHz)	{BC309	7a	TO-92	BC 550	7a	BC169, BC184, BC549, 2SC2675, 2SC3378,++
BC 239 P	Fer	Si-N	=BC 239:		40e	=TO-92	›BC 239		›BC 239
BC 238 [Riz]	Riz	Si-P	NF, -/28V, 0,5A, 0,7W, 200MHz		2a	TO-39	BC 161	2a	BC 160…161, BCX 60, 2N2303, 2SA606,++
BC 239 [Riz]	Riz	Si-P	NF, -/40V, 0,5A, 0,7W, 200MHz		2a	TO-39	BC 161	2a	BC 160…161, BCX 60, 2N2303, 2SA606,++
BC 250	Itt,Nsc	Si-P	Uni, 20/20V, 0,1A, 0,3W, 180MHz	{BC170	7a	TO-92	BC 556	7a	BC 213, BC 258, BC 308, BC 558, 2SB725++
BC 251	Itt,Nsc	Si-P	=BC 252: 50/45V	{BC171	7a	TO-92	BC 556	7a	BC 212, BC 257, BC 307, BC 557, 2SB725++
BC 252	Itt,Nsc	Si-P	Uni, 30/25V, 0,1/0,2A, 0,3W, 130MHz	{BC172	7a	TO-92	BC 556	7a	BC 213, BC 258, BC 308, BC 558, 2SB725++
BC 253	Itt,Nsc	Si-P	=BC 252: In, F<4dB(1kHz)	{BC173	7a	TO-92	BC 560	7a	BC 214, BC 259, BC 309, BC 559, 2SA1137+
BC 254 [Texas]	Tix	Si-N	Uni, 100/55V, 30mA, 0,25W		7c	TO-92	2SC2632	7c	BF 422, 2SC1890A, 2SC2631…32, 2SC3378++
BC 254(A) [Riz]	Riz	Si-N	Uni, 18/18(A=25/25)V, 0,1A, 0,3W, 120MHz		2a	TO-18	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 255 [Texas]	Tix	Si-N	=BC 254[Texas]: 0,625W		7c	TO-92	›BC 254	7a	›BC 254
BC 255(A) [Riz]	Riz	Si-N	Uni, 18/18(A=25/25)V, 0,1A, 0,3W, 120MHz		2a	TO-18	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 256	Itt,Mot	Si-P	Uni, 64/64, 0,1/0,2A, 0,3W, 130MHz	{BC174	7a	TO-92	BC 556	7a	BC 212, BC 266, BC 556, 2SA1137, 2SB725+
BC 257	Sie	Si-P	=BC 307:	{BC167	7c	TO-92	›BC 307		›BC 307
BC 258	Sie	Si-P	=BC 308:	{BC168	7c	TO-92	›BC 308		›BC 308
BC 259	Sie	Si-P	=BC 309:	{BC169	7c	TO-92	›BC 309		›BC 309
BC 260	Itt	Si-P	Uni, 20/20V, 0,1A, 0,3W, 180MHz		2a	TO-18	BC 556	7a	BC 213, BC 258, BC 308, BC 558, 2SB725++
BC 261	Itt	Si-P	=BC 262: 50/45V	{BC107	2a	TO-18	BC 556	7a	BC 212, BC 257, BC 307, BC 557, 2SB725++
BC 262	Itt	Si-P	Uni, 30/25V, 0,1/0,2A, 0,3W, 130MHz	{BC108	2a	TO-18	BC 556	7a	BC 213, BC 258, BC 308, BC 558, 2SB725++
BC 263	Itt	Si-P	=BC 262: In, F<4dB(1kHz)	{BC109	2a	TO-18	BC 560	7a	BC 241, BC 259, BC 309, BC 559, 2SA1137+
BC 264	Phi,Mot,++	N-FET	LF Inp In, 30V, Idss=2…12mA, Up=0,2…1,6V, F<2dB		7f	SOT-30	BF 245	7f	BF 244, BF 245, BFS 71, 2N3822, ++
BC 264 L	Tix	N-FET	=BC 264:		7e	TO-92	›BC 264		›BC 264
BC 266	Itt	Si-P	=BC 261: 64/64V	{BC190	2a	TO-18	BC 556	7a	BC 256, BC 556, 2SA1136…1137, 2SA1335++
BC 267	Sgs	Si-N	=BC 268: 50/45V		2a	TO-18	BC 337	7a	BC 337, BC 637, 2SC4485, 2SD1616,++
BC 268	Sgs	Si-N	Uni, 30/20V, 0,5/1A, 0,375W, 200MHz		2a	TO-18	BC 337	7a	BC 337…338, BC 635, 2SC3377, 2SD1225,++
BC 269	Sgs	Si-N	=BC 268: In, F<4dB(1kHz)		2a	TO-18	BC 337	7a	BC 337…338, BC 635, 2SC3377, 2SD1225,++
BC 270	Sgs	Si-N	=BC 268: 20/20V		2a	TO-18	BC 337	7a	BC 337…338, BC 635, 2SC3377, 2SD1225,++
BC 271	Sgs	Si-N	Uni, 25/25V, 1A, 0,3W, 225MHz		2a	TO-18	BC 337	7a	BC 337…338, BC 635, 2SC3377, 2SD1225,++
BC 272	Sgs	Si-N	Uni, 45/45V, 1A, 0,3W, 150MHz		2a	TO-18	BC 337	7a	BC 337, BC 635, 2SC4485, 2SD1616,++
BC 274	Tho	Si-P	=BC 275: 50/45V	{BC277	8a	TO-106	BC 556	7a	BC 212, BC 257, BC 307, BC 557, 2SB725++
BC 275	Tho	Si-P	Uni, 30/25V, 0,1A, 0,33W, 130MHz	{BC278	8a	TO-106	BC 556	7a	BC 213, BC 258, BC 308, BC 558, 2SB725++
BC 276	Tho	Si-P	=BC 275: In, F<4dB(1kHz)	{BC279	8a	TO-106	BC 560	7a	BC 214, BC 259, BC 309, BC 559, 2SA1137+
BC 277	Tho	Si-N	=BC 278: 45/45V	{BC274	8a	TO-106	BC 546	7a	BC 167, BC 183, BC 237, BC 547, 2SD767++
BC 278	Tho	Si-N	Uni, 20/20V, 0,1A, 0,3W, 150MHz	{BC275	8a	TO-106	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 279	Tho	Si-N	=BC 278: In, F<4dB(1kHz)	{BC276	8a	TO-106	BC 550	7a	BC 169, BC 184, BC 239, BC 549, 2SC2675+
BC 280	Sgs	Si-N	LF, In, 45/40V, 0,1A, 0,36W, 130…250MHz		2a	TO-18	BC 550	7a	BC 184, BC 413…414, BC 550, 2SC2675,++
BC 281	Sgs	Si-P	LF, In, 45/45V, 0,2A, 0,36W, 130…250MHz		2a	TO-18	BC 560	7a	BC 214, BC 415…416, BC 560, 2SA1137,++
BC 282	Sgs	Si-N	LF Drv, 60/30V, 0,6A, 0,4W, 170MHz	{BC283	2a	TO-13	BC 337	7a	BC 337, BC 637, 2SC4485, 2SD1616,++
BC 283	Sgs	Si-P	LF Drv, 30/30V, 0,6A, 0,4W, 110MHz		2a	TO-18	BC 327	7a	BC 327, BC 636, 2SA1705, 2SB1116,++
BC 284	Sgs	Si-N	Uni, 40/40V, 0,2A, 0,5W, 60MHz		2a	TO-18	BC 546	7a	BC 167, BC 183, BC 237, BC 547, 2SD767++
BC 285	Sgs	Si-N	Nixie, Uni, 120/120V, 0,1A, 0,36W, 80MHz		2a	TO-18	2SC2632	7c	BF 422, 2SC2240, 2SC2631…32, 2SC3378,++
BC 286	Sgs	Si-N	LF Drv,Out, 70/60V, 1A, 0,8W, 100MHz	{BC287	2a	TO-39	BC 141	2a	BC 140…141, BCX 40, 2N3019…3020, ++
BC 287	Sgs	Si-P	LF Drv,Out, 60/60V, 1A, 0,8W, 200MHz	{BC286	2a	TO-39	BC 161	2a	BC 161, BC 461, BCX 60, 2N4235…4236, ++
BC 288	Sgs	Si-N	LF Out, 80/40V, 5A, 0,8W, 80MHz		2a	TO-39	(BD 189)[4]	14h	BFT 32…34, BDX 35…37, 2N5336…5339
BC 289	Sgs	Si-N	Uni, 45/40V, 0,1A, 0,36W	{BC291	2a	TO-18	BC 546	7a	BC 167, BC 183, BC 237, BC 547, 2SD767++
BC 290	Sgs	Si-N	=BC 289: In, F<4dB(1kHz)	{BC292	2a	TO-18	BC 550	7a	BC 184, BC 413…414, BC 550, 2SC2675,++
BC 291	Sgs	Si-P	Uni, 45/45V, 0,2A, 0,36W	{BC289	2a	TO-18	BC 556	7a	BC 213, BC 257, BC 307, BC 557, 2SB725++
BC 292	Sgs	Si-P	=BC 291: In, F<3dB(1kHz)	{BC290	2a	TO-18	BC 560	7a	BC 214, BC 415…416, BC 560, 2SA1137,++
BC 293	Sgs	Si-N	TV-HA, 80/60V, 5A, 0,8W/7W(Tc=25°), 80MHz		2a	TO-39			BFT 32…34, BDX 35…37, 2N5336…5339
BC 294	Sgs,Tix	Si-P	LF Drv, 60/60V, 0,5A, 0,6W		2a	TO-39	BC 161	2a	BC 161, BC 303…304, BC 461, BCX 60
BC 295	Sgs	Si-N	LF Inp, 30/30V, 0,05A, 0,2W, 90MHz		8a	TO-106	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SC2390+
BC 296		Si-P							
BC 297	Sgs	Si-P	LF Drv, 50/45V, 1A, 0,375W, 250MHz	{BC377	2a	TO-18	BC 327	7a	BC 327, BC 636, BC 638, BC 640, 2SB1116+
BC 298	Sgs	Si-P	=BC 297: 30/25V	{BC378	2a	TO-18	BC 327	7a	BC 327…328, BC 636, 2SA1705, 2SB909,++
BC 299	Sgs	Si							
BC 300	Sgs	Si-N	LF Drv,Out, 120/80V, 0,5/1A, 0,85W, 120MHz		2a	TO-39	(BC 141)[7]	2a	2N1893(A), 2N2102, 2N3019…3020, ++
BC 301	Sgs	Si-N	=BC 300: 90/60V	{BC303	2a	TO-39	BC 141	2a	BC 141, BCX 40, 2N1990, 2N2102, ++
BC 302	Sgs	Si-N	=BC 300: 60/45V	{BC304	2a	TO-39	BC 141	2a	BC 140…141, BCX 40, 2N1990, 2N2102, ++
BC 303	Sgs	Si-P	LF Drv,Out, 85/60V, 0,5/1A, 0,85W, 75MHz	{BC301	2a	TO-39	BC 161	2a	BC 461, BCX 60, 2N4236
BC 304	Sgs	Si-P	=BC 303: 60/45V	{BC302	2a	TO-39	BC 161	2a	BC 161, BCX 60, BC 461, 2N4235…4236
BC 307	EUR	Si-P	=BC 308: 50/45V	{BC237	7a	TO-92	BC 556	7a	BC 212, BC 257, BC 557, 2SA970, 2SB725++
BC 307 P	Fer	Si-P	=BC 307:		40e	=TO-92	›BC 307		›BC 307
BC 308	EUR	Si-P	Uni, 30/25V, 0,1/0,2A, 0,3W, 130MHz	{BC238	7a	TO-92	BC 556	7a	BC 213, BC 258, BC 558, 2SA970, 2SB725++
BC 308 P	Fer	Si-P	=BC 308:		40e	=TO-92	›BC 308		›BC 308
BC 309	EUR	Si-P	=BC 308: 25V, In, F<4dB(1kHz)	{BC239	7a	TO-92	BC 560	7a	BC213, BC259, BC559, 2SA1137, 2SA1335,++
BC 309 P	Fer	Si-P	=BC 309:		40e	=TO-92	›BC 309		›BC 309
BC 310	Sgs	Si-N	LF Drv,Out, 70/70V, 1A, 0,8W, 90MHz	{BC311	2a	TO-39	BC 141	2a	BC 140…141, BCX 40, 2N3019…3020, ++
BC 311	Sgs	Si-P	LF Drv,Out, 70/70V, 1A, 0,8W, 200MHz	{BC310	2a	TO-39	BC 161	2a	BC 161, BC 461, BCX 60, 2N4235…4236

Original	Fabric.	Constr.	Info	Compl.	Fig.		JAEGER	Fig.	International
BC 312	Sgs	Si-N	LF, 100/100V, 0,15A, 0,8W		2a	TO-39	BC 141	2a	BC 141, BC 300, BF 257…259, ++
BC 313	Tho	Si-P	LF Drv,Out, 60/40V, 1A, 0,8W, 200MHz	BC211	2a	TO-39	BC 161	2a	BC 161, BC 461, BCX 60, 2N4235…4236
BC 313 A		Si-P	=BC 211: 80/60V		2a	TO-39	(BC 161)[7]	2a	BC 461, BCX 60, 2N4236
BC 314	Sgs	Si-N	Uni, 120/120V, 0,05A, 0,18W, >50MHz		8a	TO-106	2SC2632	7c	BF 422, 2SC1890A, 2SC2240, 2631…32,++
BC 315	Tix	Si-P	LF Inp In,45/35V, 0,1A, 0,3W, >200MHz, F<2dB(1kHz)		7a	SOT-30	BC 560	7a	BC 212, BC 415…416, BC 560, 2SA1137,++
BC 317	Fch,Mot,++	Si-N	=BC 318: 50/45V	BC320	7e	TO-92	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BC 318	Fch,Mot,++	Si-N	Uni, 40/30V, 0,15/0,3A, 0,35W, 280MHz	BC321	7e	TO-92	BC 546	7a	BC 167, BC 183, BC 237, BC 547, 2SD767++
BC 319	Fch,Mot,++	Si-N	=BC 318: 30/20V, In, F<4dB(1kHz)	BC322	7e	TO-92	BC 550	7a	BC 169, BC 184, BC 239, BC 549, 2SC2675+
BC 320	Fch,Mot,++	Si-P	=BC 321: 50/45V	BC317	7e	TO-92	BC 556	7a	BC 212, BC 257, BC 307, BC 557, 2SB725++
BC 321	Fch,Mot,++	Si-P	Uni, 45/30V, 0,15/0,3A, 0,31W, 250MHz	BC318	7e	TO-92	BC 556	7a	BC 213, BC 257, BC 307, BC 557, 2SB725++
BC 322	Fch,Mot,	Si-P	=BC 321: 30/20V, In, F<4dB(1kHz)	BC319	7e	TO-92	BC 560	7a	BC 214, BC 259, BC 309, BC 559, 2SA1137+
BC 323	Sgs	Si-N	TV-VA, 100/60V, 5A, 0,8W/7W(Tc=25°), 100MHz		2a	TO-39	(BD 189)[4]	14h	BFT 33…34, BDX 35…37, 2N5339…5339
BC 324	Sgs	Si-N	TV-VA, 85/55V, 1A, 0,8W/4W(Tc=25°), 100MHz		2a	TO-39	BC 141	2a	BC 140…141, BCX 40, 2N3019…3020, ++
BC 325	Tix	Si-P	LF In, 60/60V, 50mA, 0,36W, hFE=40…120, F<4dB		2a	TO-18	BC 560	7a	BC 214, BC 415…416, BC 560, 2SA1137,++
BC 326	Tix	Si-P	=BC 325: hFE=100…500, F<3dB(1kHz)		2a	TO-18	BC 560	7a	BC 214, BC 415…416, BC 560, 2SA1137,++
BC 327	EUR	Si-P	LF Drv, 50/45V, 0,8/1A, 0,625W, 100MHz	BC337	7a	TO-92	BC 327	7a	BC 638, BC 640, 2SB1116(A), 2SB1437,++
BC 327 A	Phi	Si-P	=BC 327: 60/60V		7a	TO-92	BC 640	7c	BC 638, BC 640, 2SB1116(A), 2SB1437,++
BC 327 L	Tix	Si-P	=BC 327:		7c	TO-92	›BC 327		›BC 327
BC 327 P	Fer	Si-P	=BC 327:		40e	=TO-92	›BC 327		›BC 327
BC 328	EUR	Si-P	=BC 327: 30/25V	BC338	7a	TO-92	BC 327	7a	BC 636, BC 638, 2SB909, 2SB1116(A),++
BC 328 L	Tix	Si-P	=BC 328:		7c	TO-92	›BC 328		›BC 328
BC 328 P	Fer	Si-P	=BC 328:		40e	=TO-92	›BC 328		›BC 328
BC 329	Tix	Si-N	LF Inp In, 60/60V, 30mA, 0,25W, F<2dB(1kHz)		7a	SOT-30	BC 550	7a	BC 184, BC 413…414, BC 550, 2SC2675,++
BC 330	Tix	Si-N	=BC 329: 45/45V		7a	SOT-30	BC 550	7a	BC 184, BC 413…414, BC 550, 2SC2675,++
BC 331	Tix	Si-N	LF Inp In, 60/60V, 30mA, 0,25W, F<6dB(1kHz)		7a	SOT-30	BC 550	7a	BC 184, BC 413…414, BC 550, 2SC2675,++
BC 332	Tix	Si-N	=BC 321: 45/45V		7a	SOT-30	BC 550	7a	BC 184, BC 413…414, BC 550, 2SC2675,++
BC 333	Mot	Si-N	Uni, 25/25V, 50mA, 0,31W, 50MHz	BC334	7e	TO-92	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 334	Mot	Si-P	Uni, 25/25V, 50mA, 0,31W, 50MHz	BC333	7e	TO-92	BC 556	7a	BC 213, BC 258, BC 308, BC 558, 2SB725++
BC 335	Mot	Si-N	=BC 333: In, F<3dB(1kHz)	BC336	7e	TO-92	BC 550	7a	BC 169, BC 184, BC 239, BC 549, 2SC2675+
BC 336	Mot	Si-P	=BC 334: In, F<3dB(1kHz)	BC335	7e	TO-92	BC 560	7a	BC 214, BC 259, BC 309, BC 559, 2SA1137+
BC 337	EUR	Si-N	LF Drv, 50/45V, 0,8/1A, 0,625W, 100MHz	BC327	7a	TO-92	BC 337	7a	BC 637, BC 639, 2SD1616(A), 2SD2181,++
BC 337 A	Phi	Si-N	=BC 337: 60/60V		7a	TO-92	BC 639	7c	BC 637, BC 639, 2SD1616(A), 2SD2181,++
BC 337 L	Tix	Si-N	=BC 337:		7c	TO-92	›BC 337		›BC 337
BC 337 P	Fer	Si-N	=BC 337:		40e	=TO-92	›BC 337		›BC 337
BC 338	EUR	Si-N	=BC 337: 30/25V	BC328	7a	TO-92	BC 337	7a	BC 635, BC 637, 2SD1225, 2SD1616(A),++
BC 338 L	Tix	Si-N	=BC 338:		7c	TO-92	›BC 338		›BC 338
BC 338 P	Fer	Si-N	=BC 338:		40e	=TO-92	›BC 338		›BC 338
BC 340	Itt	Si-N	LF Drv,Out, 40/40V, 0,5A, 0,8W, 100MHz	BC360	2a	TO-39	BC 141	2a	BC 140…141, BC 300…302, 2N1990, ++
BC 341	Itt	Si-N	=BC 340: 60/60V	BC361	2a	TO-39	BC 141	2a	BC 140…141, BC 300…302, 2N1990, ++
BC 342	Mot	Si-N	LF Drv,Out, 70/60V, 1A, 0,8W, 100MHz	BC343	2a	TO-39	BC 141	2a	BC 140…141, BCX 40, 2N3019…3020, ++
BC 343	Mot	Si-P	LF Drv,Out, 70/60V, 1A, 0,8W, 100MHz	BC342	2a	TO-39	BC 161	2a	BC 161, BCX 60, 2N4236, ++
BC 344	Mot	Si-N	=BC 342: 90/80V	BC345	2a	TO-39	BC 141	2a	BC 141, BCX 40, 2N3019…3020, ++
BC 345	Mot	Si-P	=BC 343: 90/80V	BC344	2a	TO-39	BC 161	2a	BC 461, BCX 60
BC 347	Mot	Si-N	Uni, 50/45V, 0,1A, 0,3W, >125MHz	BC350	7e	TO-92	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BC 348	Mot	Si-N	=BC 347: 40/30V	BC351	7e	TO-92	BC 546	7a	BC 167, BC 183, BC 237, BC 547, 2SD767++
BC 349	Mot	Si-N	=BC 347: 30/20V	BC352	7e	TO-92	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 350	Mot	Si-P	Uni, 50/45V 0,1A, 0,3W, >125MHz	BC347	7e	TO-92	BC 556	7a	BC 212, BC 257, BC 307, BC 557, 2SB725++
BC 351	Mot	Si-P	=BC 350: 40/30V	BC348	7e	TO-92	BC 556	7a	BC 213, BC 257, BC 307, BC 557, 2SB725++
BC 352	Mot	Si-P	=BC 350: 30/20V	BC349	7e	TO-92	BC 556	7a	BC 213, BC 258, BC 308, BC 558, 2SB725++
BC 354	Mot	Si-P	Uni, 30/25V, 0,2A, 0,31W, >200MHz		7e	TO-92	BC 556	7a	BC 213, BC 258, BC 308, BC 558, 2SB725++
BC 355	Mot	Si-P	Uni, 30/25V, 0,2A, 0,31W, >200MHz		7e	TO-92	BC 556	7a	BC 213, BC 258, BC 308, BC 558, 2SB725++
BC 357	Mot	Si-P	Uni, 25/25V, 0,1A, 0,31W, >125MHz	BC358	7e	TO-92	BC 556	7a	BC 213, BC 258, BC 308, BC 558, 2SB725++
BC 358	Mot	Si-N	Uni, 25/25V, 0,1A, 0,31W, >125MHz	BC357	7e	TO-92	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 360	Itt	Si-P	LF Drv,Out, 40/40V, 0,5A, 0,8W, 250MHz	BC340	2a	TO-39	BC 161	2a	BC 160…161, BC 303…304, BCX 60, ++
BC 361	Itt	Si-P	=BC 360: 60/60V	BC341	2a	TO-39	BC 161	2a	BC 161, BC 303…304, BCX 60, ++
BC 362	Mot	Si-P	LF P, 50/45V, 2A, 8W, 100MHz	BC365	13m	(Uniwatt)	(2SA1593)[4]	30j	BD 518, BD 526, (2SB838…839, 2SB1201++)[4]
BC 363	Mot	Si-P	=BC 362: 60/60V	BC366	13m	(Uniwatt)	(2SA1593)[4]	30j	BD 518, BD 526, (2SB839, 2SB1201,++)[4]
BC 364	Mot	Si-P	=BC 362: 80/80V	BC367	13m	(Uniwatt)	(2SA1593)[4]	30j	BD 520, BD 528, (2SB839, 2SB957…958,++)[4]
BC 365	Mot	Si-N	LF P, 50/45V, 2A, 8W, 150MHz	BC362	13m	(Uniwatt)	(2SC4135)[4]	30j	BD 517, BD 525, (2SD1078…79, 2SD1801++)[4]
BC 366	Mot	Si-N	=BC 365: 60/60V	BC363	13m	(Uniwatt)	(2SC4135)[4]	30j	BD 517, BD 525, (2SD1079, 2SD1801,++)[4]
BC 367	Mot	Si-N	=BC 365: 80/80V	BC364	13m	(Uniwatt)	(2SC4135)[4]	30j	BD 519, BD 527, (2SD1281…82, 2SD1801++)[4]
BC 368	Phi,Sie,++	Si-N	LF Drv, 25/20V, 1/2A, 0,8W, 65MHz	BC369	7c	TO-92	BC 639	7c	BC 337…338, BC 635, 2SD1225, 2SD1616,++
BC 369	Phi,Sie,++	Si-P	LF Drv, 25/20V, 1/2A, 0,8W, 65MHz	BC368	7c	TO-92	BC 640	7c	BC 327…328, BC 636, 2SB909, 2SB1116,++
BC 370	Sgs	Si-P	LF Drv, 20/20V, 0,5/1A, 0,375W, 150MHz		2a	TO-18	BC 327	7a	BC 327…328, BC 636, 2SB909, 2SB1116,++
BC 371	Sgs	Si-N	LF Drv,Out, 60V, 1A, 0,85W		2a	TO-39	BC 141	2a	BC 140…141, BCX 40, 2N3019…3020, ++
BC 372	Mot	Si-N-Darl	100/100V, 1A, 0,625W, >100MHz, hFE>10000		7a	TO-92	(BC 879)[13]	7c	(BC 879, BSR 52, 2SD1660, 2SD2067,++)[13]
BC 373	Mot	Si-N-Darl	=BC 372: 80/80V		7a	TO-92	(BC 879)[13]	7c	(BC 877, BC 879, BSR 51…52, 2SD1853,++)[13]
BC 375	Phi	Si-N	LF Drv,Out, 30/30V, 1/1,5A, 0,625W, 150MHz	BC376	7a	TO-92	BC 337	7a	BC 337…338, BC 635, 2SD1225, 2SD1616,++
BC 376	Phi	Si-P	LF Drv,Out, 30/30V, 1/1,5A, 0,625W, 100MHz	BC375	7a	TO-92	BC 327	7a	BC 327…328, BC 636, 2SB909, 2SB1116,++
BC 377	Sgs	Si-N	LF Drv, 50/45V, 1A, 0,375W, 200MHz	BC297	2a	TO-18	BC 337	7a	BC337, BC637, BC639, 2SC4485, 2SD1616,++
BC 378	Sgs	Si-N	=BC 377: 30/25V	BC298	2a	TO-18	BC 337	7a	BC 337…338, BC 635, 2SC4485, 2SD1225,++
BC 381	Tix	Si-P	Uni, 40/25V, 0,2A, 0,625W		7a	SOT-30	BC 327	7a	BC 327, BC 636, BC 638, 2SA1515,++
BC 382	Tix	Si-N	LF In, 50/45V, 0,1A, 0,3W, >150MHz		7a	SOT-30	BC 550	7a	BC 184, BC 413…414, BC 550, 2SC2675,++
BC 383	Tix	Si-N	=BC 382: 45/30V		7a	SOT-30	BC 550	7a	BC 184, BC 413…414, BC 550, 2SC2675,++
BC 384	Tix	Si-N	=BC 382: 45/30V, Ur<0,135µV		7a	SOT-30	BC 550	7a	BC 184, BC 413…414, BC 550, 2SC2675,++
BC 385	Tix	Si-N	Uni, 45/45V, 0,1/0,2A, 0,3W, >150MHz		7a	SOT-30	BC 546	7a	BC 167, BC 183, BC 237, BC 547, 2SD767++
BC 386	Tix	Si-N	Uni, 45V, 0,1A, 0,3W, >150MHz		7a	SOT-30	BC 546	7a	BC 167, BC 183, BC 237, BC 547, 2SD767++
BC 387	Mot	Si-N	LF Drv, 35/30V, 0,6A, 0,31W	BC388	7e	TO-92	BC 337	7a	BC337, BC635, BC637, 2SC4485, 2SD1225,++
BC 388	Mot	Si-P	LF Drv, 35/30V, 0,6A, 0,31W	BC387	7e	TO-92	BC 327	7a	BC 327, BC 536, BC 638, 2SA1705, 2SB909+
BC 389	Sgs	Si-N	Uni, -/45V, 0,2A, 0,3W, >150MHz, hFE>40		2a	TO-18	BC 546	7a	BC 167, BC 183, BC 237, BC 547, 2SD767++
BC 390	Sgs	Si-N	=BC 389: -/20V		2a	TO-18	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 391	Sgs	Si-N	=BC 389: -/20V, hFE>100		2a	TO-18	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 393	Mot,Sgs	Si-P	LF,Vid, 180/180V, 0,1A, 0,4W, 120MHz	BC394	2a	TO-18	BF 421 A	7c	BF 423, BF436…37, BF 491…93, 2SB1349++
BC 394	Mot,Sgs	Si-N	LF,Vid, 180/160V, 0,1A, 0,4W, 90MHz	BC393	2a	TO-18	BF 420 A	7c	BF 298…99, BF 391…93, BF 423, 2SD2031+
BC 395	Sgs	Si-N	TV-VA Drv, 80/70V, 0,5A, 0,3W, >60MHz	BC396	8a	TO-105	BC 141	2a	BC 140…41, BC 300…01, BC 639, 2SD2181+
BC 396	Sgs	Si-P	TV-VA Drv,80/70V, 0,5A, 0,3W	BC395	8a	TO-105	BC 161	2a	BC 303, BC 640, 2SA1708, 2SB1437,++
BC 397	Sgs	Si-P	LF Drv,Out, 50/40V, 1A, 0,8W		2a	TO-5	BC 161	2a	BC 161, BC 460…461, BCX 60, ++
BC 398	Sgs	Si-N	LF Drv,Out, 60/50V, 1A, 0,8W		2a	TO-5	BC 141	2a	BC 140…141, BC 440…441, BCX 40, ++
BC 399	Sgs	Si-N	Min, LF In, 30/20V, 75mA, 75mW		36a	(2x1,8mm)	(BC 550)[6]	7a	BC 122…123
BC 400	Sgs	Si-P	Uni, 90/80V, 50mA, 0,2W, 150MHz		8a	TO-106	BC 556	7a	BC 477, 2SA893(A), 2SA1017, SB715, ++
BC 404	Sgs	Si-P	Uni, 80/60V, 0,15A, 0,36W, 150MHz		7a	TO-92	BC 556	7a	BC 477, BC 556, 2SA1136…37, 2SA1335,++
BC 405	Sgs	Si-P	=BC 404: 60/60V, In, F<4dB(1kHz)		7a	TO-92	BC 560	7a	BC 416, BC 560, 2SA1136…1137, 2SA1335++
BC 406	Sgs	Si-P	=BC 404: 40/40V, In, F<2dB(1kHz)		7a	TO-92	BC 560	7a	BC214, BC415…416, BC 560, 2SA1136…37++

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BC 407	Phi	Si-N	=BC 237:	{BC417	8a	TO-106	›BC 237		›BC 237
BC 408	Phi	Si-N	=BC 238:	{BC418	8a	TO-106	›BC 237		›BC 238
BC 409	Phi	Si-N	=BC 239:	{BC419	8a	TO-106	›BC 550		›BC 239
BC 410	Sgs	Si-N	Uni, 30/30V, 50mA, 0,25W		8a	TO-106	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SC1890+
BC 411	Sgs	Si-N	LF Drv,Out, 85V, 1A, 0,3W, 80MHz		8a	TO-105	BC 141	2a	BC 140…141, BCX 40, BC 639, 2SD667(A)++
BC 412	Sgs	Si-N	LF Drv, 75/35V, 1A, 0,5W, 90MHz		2a	TO-18	BC 639	7c	BC 639, 2SD667(A), 2SD774, 2SD1616A,++
BC 413	EUR	Si-N	Uni, In, 45/30V, 0,1A, 0,3W, 250MHz	{BC415	7a	TO-92	BC 550	7a	BC 184, BC 550, 2SC2674…75, 2SC3378,++
BC 414	EUR	Si-N	=BC 413: 50/45V	{BC416	7a	TO-92	BC 550	7a	BC 184, BC 550, 2SC2674…75, 2SC3378,++
BC 415	EUR	Si-P	Uni, In, 45/35V, 0,1A, 0,3W, 200MHz	{BC413	7a	TO-92	BC 560	7a	BC 214, BC 560, 2SA1136…37, 2SA1335,++
BC 416	EUR	Si-P	=BC 415: 50/45V	{BC414	7a	TO-92	BC 560	7a	BC 214, BC 560, 2SA1136…37, 2SA1335,++
BC 413P…416P	Fer	Si-N/P	=BC 413…416:		40e	=TO-92	›BC 413…416		›BC 413…416
BC 417	Phi	Si-P	=BC 307:	{BC407	8a	TO-106	›BC 307		›BC 307
BC 418	Phi	Si-P	=BC 308:	{BC408	8a	TO-106	›BC 308		›BC 308
BC 419	Phi	Si-P	=BC 309:	{BC409	8a	TO-106	›BC 309		›BC 309
BC 420	Sgs	Si-P	Vid, 180/180V, 0,1A, 0,4W, 150MHz		2a	TO-18	BF 421 A	7c	BF 423, BF 435…437, BF 491…493, ++
BC 424	Mot	Si-N	LF Drv, 80/60V, 0,5A, 0,5W, >50MHz	{BC426	7e	TO-92	BC 639	7c	BC 639, 2SD1226, 2SD1616A, 2SD1768,++
BC 425	Mot	Si-N	=BC 424: 60/60V	{BC427	7e	TO-92	BC 639	7c	BC 637, BC 639, 2SD1226, 2SD1616A,++
BC 426	Mot	Si-P	LF Drv, 80/80V, 0,5A, 0,5W, >50MHz	{BC424	7e	TO-92	BC 640	7c	BC 640, 2SB910, 2SB1116A, 2SB1437,++
BC 427	Mot	Si-P	=BC 426: 60/60V	{BC425	7e	TO-92	BC 640	7c	BC 638, BC 640, 2SB910, 2SB1116A,++
BC 429	Tix	Si-N	LF Drv,Out, 45/45V, 1A, 6W, >100MHz	{BC430	14h	TO-126	BD 139	14h	BD 135, BD 137, BD 139, BD 226, ++
BC 429 A		Si-N	=BC 429: 60/60V		14h	TO-126	BD 139	14h	BD 137, BD 139, BD 228, BD 230, ++
BC 430	Tix	Si-P	LF Drv,Out, 45/45V, 1A, 6W, >100MHz	{BC429	14h	TO-126	BD 140	14h	BD 136, BD 138, BD 140, BD 227, ++
BC 430 A		Si-P	=BC 430: 60/60V		14h	TO-126	BD 140	14h	BD 138, BD 140, BD 229, BD 231, ++
BC 431	Aeg	Si-N	LF Drv, 70/60V, 0,8/1A, 0,5W, 100MHz	{BC432	7a	TO-92	BC 639	7c	BC 639, 2SD1616A, 2SD1768, 2SD2181,++
BC 432	Aeg	Si-P	LF Drv, 70/60V, 0,8/1A, 0,5W, 100MHz	{BC431	7a	TO-92	BC 640	7c	BC 640, 2SB984, 2SB1116A, 2SB1437,++
BC 437	Hit	Si-N	=BC 438: 50V		9a	(5x6x3mm)	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BC 438	Hit	Si-N	Uni, 30/20V, 0,1A, 0,22W, 300MHz		9a	(5x6x3mm)	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 439	Hit	Si-N	=BC 438: In, F<4dB(1kHz)		9a	(5x6x3mm)	BC 550	7a	BC 169, BC 184, BC 239, BC 549, 2SC2675+
BC 440	Sgs	Si-N	LF Drv,Out, 50/40V, -/2A, 1W, >50MHz	{BC460	2a	TO-39	(BD 139)[4]	14h	BCX 40, 2N4237…4239, 2SC2214
BC 441	Sgs	Si-N	=BC 440: 75/60V	{BC461	2a	TO-39	(BD 139)[4]	14h	BCX 40, 2N4238…4239, 2SC2214
BC 445	Itt,Mot	Si-N	Uni, 60/60V, 0,3A, 0,625W, >100MHz	{BC446	7e	TO-92	BC 546	7a	BC 182, BC 546, BC 637, BC 639, 2SC4414+
BC 446	Itt,Mot	Si-P	Uni, 60/60V, 0,3A, 0,625W, >100MHz	{BC445	7e	TO-92	BC 556	7a	BC 212, BC 556, BC 638, BC 640, 2SA1683+
BC 447	Itt,Mot	Si-N	=BC 445: 80/80V	{BC448	7e	TO-92	BC 546	7a	BC 546, BC 639, 2SC4414, 2SD1226,++
BC 448	Itt,Mot	Si-P	=BC 446: 80/80V	{BC447	7e	TO-92	BC 556	7a	BC 556, BC 640, 2SA1683, 2SB910,++
BC 449	Itt,Mot	Si-N	=BC 445: 100/100V	{BC450	7e	TO-92	(BC 546)[7]	7a	BC 639, 2SC4414, 2SC3665, 2SD1225,++
BC 450	Itt,Mot	Si-P	=BC 446: 100/100V	{BC449	7e	TO-92	(BC 556)[7]	7a	BC 640, 2SA1683, 2SB984, 2SB910,++
BC 451	Tos	Si-N	Uni, 50/45V, 0,1A, 0,3W, >150MHz	{BC454	7a	TO-92	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BC 452	Tos	Si-N	=BC 451: 30/30V	{BC455	7a	TO-92	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 453	Tos	Si-N	=BC 451: 30/30V, In, F<4dB(1kHz)	{BC456	7a	TO-92	BC 550	7a	BC 169, BC 184, BC 239, BC 549, 2SC2675+
BC 454	Tos	Si-P	Uni, 50/45V, 0,1A, 0,3W, >150MHz	{BC451	7a	TO-92	BC 556	7a	BC 212, BC 257, BC 307, BC 557, 2SB725++
BC 455	Tos	Si-P	=BC 454: 30/30V	{BC452	7a	TO-92	BC 556	7a	BC 213, BC 258, BC 308, BC 558, 2SB725++
BC 456	Tos	Si-P	=BC 454: 30/30V, In, F<4dB(1kHz)	{BC453	7a	TO-92	BC 560	7a	BC 214, BC 259, BC 309, BC 559, 2SA1137+
BC 460	Sgs	Si-P	LF Drv,Out, 50/45V, -/2A, 1W, >50MHz	{BC440	2a	TO-39	(BD 140)[4]	14h	BCX 60, 2N4235…4236
BC 461	Sgs	Si-P	=BC 460: 75/60V	{BC441	2a	TO-39	(BD 140)[4]	14h	BCX 60, 2N4236
BC 462	Phi	Si-P	LF Drv,Out, 35/28V, 1,5A, 0,88W, 200MHz	{BC463	11a	SOT-25	BC 640	7c	BC 636, BC 638, BC 640, 2SA966, 2SB819++
BC 463	Phi	Si-N	LF Drv,Out, 35/28V, 1,5A, 0,88W, 200MHz	{BC462	11a	SOT-25	BC 639	7c	BC635, BC637, BC639, 2SC2236, 2SD1051,++
BC 464	Phi	Si-P	=BC 462: 25/18V	{BC465	11a	SOT-25	BC 640	7c	BC 636, BC 638, BC 640, 2SA966, 2SB819++
BC 465	Phi	Si-N	=BC 463: 25/18V	{BC464	11a	SOT-25	BC 639	7c	BC635, BC637, BC639, 2SC2236, 2SD1051,++
BC 467	Hit	Si-N	=BC 468: 50/45V		9b	(5x6x3mm)	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BC 468	Hit	Si-N	Uni, 30/20V, 0,1A, 0,22W, 300MHz		9b	(5x6x3mm)	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 469	Hit	Si-N	=BC 468: In, F<4dB(1kHz)		9b	(5x6x3mm)	BC 550	7a	BC 169, BC 184, BC 239, BC 549, 2SC2675+
BC 477	Sgs	Si-P	Uni, 90/80V, 0,15A, 0,36W, 150MHz		2a	TO-18	BC 556	7a	BC 556, 2SA1285(A), 2SA970, 2SA1335,++
BC 478	Sgs	Si-P	=BC 477: 40/40V		2a	TO-18	BC 556	7a	BC 213, BC 257, BC 307, BC 557, 2SB725++
BC 479	Sgs	Si-P	=BC 477: 40/40V, In, F<4dB(1kHz)		2a	TO-18	BC 560	7a	BC 214, BC 415…416, BC 560, 2SA1137,++
BC 485	Mot,Nsc	Si-N	LF Drv,Out, 45/45V, 1A, 0,625W, 200MHz	{BC486	7e	TO-92	BC 639	7c	BC 337, BC 635, BC 637, 2SD1616(A),++
BC 486	Mot,Nsc	Si-P	LF Drv,Out, 45/45V, 1A, 0,625W, 200MHz	{BC485	7e	TO-92	BC 640	7c	BC 327, BC 636, BC 638, 2SB1116(A),++
BC 487	Mot,Nsc	Si-N	=BC 485: 60/60V	{BC488	7e	TO-92	BC 639	7c	BC 637, BC 639, 2SC4485, 2SD1616A,++
BC 488	Mot,Nsc	Si-P	=BC 486: 60/60V	{BC487	7e	TO-92	BC 640	7c	BC 638, BC 640, 2SA1705, 2SB1116A,++
BC 489	Mot,Nsc	Si-N	=BC 485: 80/80V	{BC490	7e	TO-92	BC 639	7c	BC 639, 2SD667, 2SD1616A, 2SD2181,++
BC 490	Mot,Nsc	Si-P	=BC 486: 80/80V	{BC489	7e	TO-92	BC 640	7c	BC 640, 2SB647, 2SB1116A, 2SB1437,++
BC 507	Sgs	Si-N	=BC 508: 70/45V		7a	TO-92	BC 546	7a	BC 174, BC 190, BC 546, 2SA1136…37,++
BC 508	Sgs	Si-N	Uni, 60/35V, 0,2A, 0,36W, 200MHz		7a	TO-92	BC 546	7a	BC 174, BC 182, BC 190, BC 546, 2SD767++
BC 509	Sgs	Si-N	=BC 508: In, F<dB(1kHz)		7a	TO-92	BC 550	7a	BC414, BC550, 2SC2240, 2SC2459, 2SC2675+
BC 510	Sgs	Si-N	=BC 508: 40V, In, F<2dB(1kHz)		7a	TO-92	BC 550	7a	BC 184, BC 413…414, BC 550, 2SC2675,++
BC 507F…510F		Si-N	=BC 507…510:		7a	SOT-30			›BC 507…510
BC 512	Tix	Si-P	=BC 513: 50/45V	{BC582	7a	SOT-30	BC 556	7a	BC 212, BC 257, BC 307, BC 557, 2SB725++
BC 513	Tix	Si-P	Uni, 30/30V, 0,2A, 0,3W, >200MHz	{BC583	7a	SOT-30	BC 556	7a	BC 213, BC 258, BC 308, BC 558, 2SB725++
BC 514	Tix	Si-P	=BC 513: In, F<4dB(1kHz)	{BC584	7a	SOT-30	BC 560	7a	BC 214, BC 259, BC 309, BC 559, 2SA1137+
BC 515	Sgs	Si							
BC 516(P)	Phi,Tix,++	Si-P-Darl	Uni, 40/30V, 0,4/0,8A, 0,625W, 250MHz, hFE>30k		7a	TO-92	(BC 880)[13]	7c	MPS-A75, (BC 876, BC 878, 2SA1555,++)[13]
BC 517(P)	Phi,Tix,++	Si-N-Darl	Uni, 40/30V, 0,4/0,8A, 0,625W, 220MHz, hFE>30k		7a	TO-92	(BC 879)[13]	7c	MPS-A25, (BC 875, BC 877, 2SC4017,++)[13]
BC 520	Fch	Si-N	Uni, In, 60/60V, 0,05A, 0,625W, >100MHz, hFE>180		7e	TO-92	BC 550	7a	BC414, BC550, 2SC2240, 2SC2459, 2SC2675
BC 521	Fch	Si-N	=BC 520: 45/45V, hFE=380…1550		7e	TO-92	(BC 550)[13]	7a	2SC3112…13, 2SD1010…11, (BC 550,++)[13]
BC 522	Fch	Si-N	=BC 520: 20/20V, F<3dB(1kHz), hFE=400…2200		7e	TO-92	(2SC3071)	9c(9mm)	2SC3112…13, 2SD1010…11, (BC 549,++)[13]
BC 523	Fch	Si-N	=BC 520: 45/45V, hFE=180…800		7e	TO-92	BC 550	7a	BC 184, BC 413…414, BC 550, 2SC2675,++
BC 524	Fch,Tix	Si-N	Uni, In, 45/45V, 0,1A, 0,625W, F<2dB(1kHz)		7e	TO-92	BC 550	7a	BC 184, BC 413…414, BC 550, 2SC2675,++
BC 525	Fch	Si-P	Uni, In, -/35V, 0,1A, 0,625W, F<2dB(1kHz)		7e	TO-92	BC 560	7a	BC 214, BC 415…416, BC 560, 2SA1137,++
BC 526	Fch	Si-P	Uni, 60/50V, 0,2A, 0,625W, >100MHz		7e	TO-92	BC 556	7a	BC 212, BC 256, BC 266, BC 556, 2SB725++
BC 527[Ucp]	Ucp	Si-N	Uni, 45V, 0,05A, 0,3W, 150MHz		2a	TO-18	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BC 527	Fch,Mic	Si-P	LF Drv,Out, 60/60V, 1/1,5A, 0,625W, >100MHz	{BC537	7e	TO-92	BC 640	7c	BC 638, BC 640, 2SA1705, 2SB1116(A),++
BC 528	Fch,Mic	Si-P	=BC 527: 80/80V	{BC538	7e	TO-92	BC 640	7c	BC 640, 2SA1708, 2SB647(A), 2SB1116A,++
BC 528[Ucp]	Ucp	Si-N	Uni, 45V, 0,05A, 0,3W, 150MHz		2a	TO-18	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BC 529	Fch	Si-P	Uni, 50/30V, 0,2A, 0,625W, >100MHz		7e	TO-92	BC 556	7c	BC 212, BC 556…557, BC 327, 2SA1683,++
BC 530	Fch	Si-P	Vid, 130/120V, 0,1A, 0,625W, >50MHz	{BC532	7e	TO-92	BF 421 A	7c	BF 423, BF 435…437, 2SA1370, 2SB1348,++
BC 531	Fch	Si-P	=BC 530: 160/150V	{BC533	7e	TO-92	BF 421 A	7c	BF 423, BF 435…437, 2SA1370, 2SB1349,++
BC 532	Fch	Si-N	Vid, 160/140V, 0,1A, 0,625W, >50MHz	{BC530	7e	TO-92	BF 420 A	7c	BF 420, BF 422, 2SC3467, 2SD2030…31,++
BC 533	Fch	Si-N	=BC 532: 180/160V	{BC531	7e	TO-92	BF 420 A	7c	BF 420, BF 422, 2SC3467, 2SD2031,++
BC 534	Fch	Si-P	LF Drv,Out, 80/80V, 0,5A, 0,625W, >50MHz	{BC535	7e	TO-92	BC 640	7c	BC 640, 2SA1708, 2SB910, 2SB1116A,++
BC 535	Fch	Si-N	LF Drv,Out, 80/80V, 0,5A, 0,625W, >50MHz	{BC534	7e	TO-92	BC 639	7c	BC 639, 2SC4488, 2SD1226, 2SD1616A,++
BC 537	Fch,Mic	Si-N	LF Drv,Out, 60/60V, 1/1,5A, 0,625W, >100MHz	{BC527	7e	TO-92	BC 639	7c	BC 637, BC 639, 2SC4485, 2SD1616(A),++
BC 538	Fch,Mic	Si-N	=BC 537: 80/80V	{BC528	7e	TO-92	BC 639	7c	BC 639, 2SC4488, 2SD667(A), 2SD1616A,++
BC 546	EUR	Si-N	=BC 547: 80/65V	{BC556	7a	TO-92	BC 546	7a	2SC2240, 2SC2459, 2SC2674…75, 2SC3378
BC 547	EUR	Si-N	Uni, 50/45V, 0,1/0,2A, 0,5W, 300MHz	{BC557	7a	TO-92	BC 546	7a	BC 167, BC 182, BC 237, 2SD767, 2SC2675+

Original	Fabric.	Constr.	Info	Compl.	Fig.		JAEGER	Fig.	International
BC 548	EUR	Si-N	=BC 547: 30/30V	BC558	7a	TO-92	BC 546	7a	BC 168, BC 183, BC 238, 2SD767, 2SC2675+
BC 549	EUR	Si-N	=BC 547: 30/30V, In, F<4dB(1kHz)	BC559	7a	TO-92	BC 550	7a	BC169, BC184, BC239, 2SC2675, 2SC3378,++
BC 550	EUR	Si-N	=BC 547: In, F<4dB(1kHz)	BC560	7a	TO-92	BC 550	7a	BC184, BC414, 2SC2674…75, 2SC2675,++
BC 551	Phi	Si-P	Uni, 50/45V, 0,1A, 0,5W		7a	TO-92	BC 556	7a	BC 212, BC 257, BC 307, BC 557, 2SB725++
BC 556	EUR	Si-P	=BC 557: 80/65V	BC546	7a	TO-92	BC 556	7a	2SA970, 2SA1049, 2SA1136…37, 2SA1335,++
BC 557	EUR	Si-P	Uni, 50/45V, 0,1/0,2A, 0,5W, 150MHz	BC547	7a	TO-92	BC 556	7a	BC 212, BC 257, BC 307, 2SB725, 2SA1137+
BC 558	EUR	Si-P	=BC 557: 30/30V	BC548	7a	TO-92	BC 556	7a	BC 213, BC 258, BC 308, 2SB725, 2SA1137+
BC 559	EUR	Si-P	=BC 557: 30/30V, In, F<4dB(1kHz)	BC549	7a	TO-92	BC 560	7a	BC214, BC259, BC309, 2SA1137, 2SA1335,++
BC 560	EUR	Si-P	=BC 557: In, F<4dB(1kHz)	BC550	7a	TO-92	BC 560	7a	BC 214, BC 416, 2SA1136…37, 2SA1335,++
BC 582	Tix	Si-N	=BC 583: 50/45V	BC512	7a	SOT-30	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BC 583	Tix	Si-N	Uni, 30/20V, 0,2A, 0,3W, >150MHz	BC513	7a	SOT-30	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BC 584	Tix	Si-N	=BC 583: In, F<4dB(1kHz)	BC514	7a	SOT-30	BC 550	7a	BC 169, BC 184, BC 239, BC 549, 2SC2675+
BC 585	Mot	Si-N	Temperatur Sensor, 25/20V, -/0,1A, 0,35W		7a	TO-92	(BC 546)	7a	(BC 168, BC 183, BC 238, BC 548)
BC 586	Mot	Si-P	Temperatur Sensor, 25/20V, -/0,1A, 0,35W		7a	TO-92	(BC 546)	7a	(BC 213, BC 258, BC 308, BC 558)
BC 587	Eiy	Si-P	60V, 1A, 4W(Tc=25°)		2a	TO-5	BC 161	2a	BC 161, BC 461, BCX 60, 2N4235…4236
BC 612	Tix	Si-P	Uni, 75/70V, 0,2A, 0,3W, >200MHz	BC682	7a	SOT-30	BC 556	7a	BC 556, 2SA1136…37, 2SA1335, 2SB725,++
BC 612 L		Si-P	=BC 612:		7c	TO-92	›BC 612		›BC 612
BC 617	Phi,Tix,++	Si-N-Darl	LF Drv,Out, 50/40V, 1A, 0,625W, >150MHz, hFE>10k		7a	TO-92	(BC 879)[13]	7c	(BC 875, BC 877, BC 879, BSR 50…52,++)[13]
BC 618	Phi,Tix,++	Si-N-Darl	=BC 617: 80/55V		7a	TO-92	(BC 879)[13]	7c	(BC 877, BC 879, BSR 51…52,++)[13]
BC 635	EUR	Si-N	LF Drv,Out, 45/45V, 1/1,5A, 0,8W, 130MHz	BC636	7c	TO-92	BC 639	7c	BC 537…538, 2SC4485, 2SD1616, 2SD2181++
BC 636	EUR	Si-P	LF Drv,Out, 45/45V, 1/1,5A, 0,8W, 50MHz	BC635	7c	TO-92	BC 640	7c	BC 527…528, 2SA1705, 2SB1116, 2SB1437++
BC 637	EUR	Si-N	=BC 635: 60/60V	BC638	7c	TO-92	BC 639	7c	BC 537…538, 2SC4485, 2SD1616, 2SD2181++
BC 638	EUR	Si-P	=BC 636: 60/60V	BC637	7c	TO-92	BC 640	7c	BC 527…528, 2SA1705, 2SB1116, 2SB1437++
BC 639	EUR	Si-N	=BC 635: 100/80V	BC640	7c	TO-92	BC 639	7c	2SC4488, 2SD1616A, 2SD1768, 2SD2181,++
BC 640	EUR	Si-P	=BC 636: 100/80V	BC639	7c	TO-92	BC 640	7c	2SA1708, 2SB984, 2SB1116A, 2SB1437,++
BC 650(S)	Mot	Si-N	LF In, 30/30V, 0,2A, 0,625W, 300MHz, hFE=380…2500 F<3,5dB(1kHz), S: F<2,3dB(1kHz)		7e	TO-92	(BC 550)[13]	7a	2SC3112…13, (BC 239, BC 549…550,++)[13]
BC 651(S)	Mot	Si-N	=BC 650: 45/45V		7e	TO-92	(BC 550)[13]	7a	2SC3112…13, (BC 413…414, 550,++)[13]
BC 682	Tix	Si-N	Uni, 75/70V, 0,2A, 0,3W, >150MHz	BC612	7a	SOT-30	BC 546	7a	BC 174, BC 190, BC 546, 2SC2675,2SC3378+
BC 682 L		Si-N	=BC 682:		7c	TO-92	›BC 682		›BC 682
BC 714	Tix	Si-P	Uni, In, 45/30V, 0,2A, 0,3W, >200MHz, F<2dB(1kHz)		7a	TO-92	BC 560	7a	BC 214, BC 415…416, BC 560, 2SA1137,++
BC 727	Fch,Mic	Si-P	LF Drv,Out, 50/40V, 1/2,5A, 0,625W, >100MHz	BC737	7e	TO-92	BC 640	7c	BC 638, BC 640, 2SB819, 2SB1116(A),++
BC 728	Fch,Mic	Si-P	=BC 727: 30/25V	BC738	7e	TO-92	BC 640	7c	BC 636, BC 638, 2SB819, 2SB1116(A),++
BC 737	Fch,Mic	Si-N	LF Drv,Out, 50/45V, 1/2,5A, 0,625W, >100MHz	BC727	7e	TO-92	BC 639	7c	BC 637, BC 639, 2SD1041, 2SD1616(A),++
BC 738	Fch,Mic	Si-N	=BC 737: 30/25V	BC728	7e	TO-92	BC 639	7c	BC 635, BC 637, 2SD1051, 2SD1616(A),++
BC 807	Phi,Sie,++	Si-P	=BC 327: SMD	BC817	35a	SOT-23	BC 807	35a	BCX 17, BCW 68, 2SA1366, 2SB1198
BC 807 R		Si-P	=BC 807:		35d	SOT-23			BCX 17R, BCW 68R
BC 807-W	Phi	Si-P	=BC 807:		35a(2mm)	SOT-323			2SB1219A
BC 808	Phi,Sie,++	Si-P	=BC 328: SMD	BC818	35a	SOT-23	BC 807	35a	BCX 17…18, BCW 67…68, 2SA1366, 2SB1197
BC 808 R		Si-P	=BC 808:		35d	SOT-23			BCX 17R…18R, BCW 67R…68R
BC 808-W	Phi	Si-P	=BC 808:		35a(2mm)	SOT-323			2SA1588, 2SB1219(A)
BC 817	Phi,Sie,++	Si-N	=BC 337: SMD	BC807	35a	SOT-23	BC 817	35a	BCX 19, BCW 65…66, 2SC3325, 2SC3441
BC 817 R		Si-N	=BC 817:		35d	SOT-23			BCX 19R, BCW 65R…66R
BC 817-W	Phi	Si-N	=BC 817:		35a(2mm)	SOT-323			2SD1820A, 2SD1949
BC 818	Phi,Sie,++	Si-N	=BC 338: SMD	BC808	35a	SOT-23	BC 817	35a	BCX 19…20, BCW 65…66, 2SC3265, 2SC3325
BC 818 R		Si-N	=BC 818:		35d	SOT-23			BCX 19R…20R, BCW 65R…66R
BC 818-W	Phi	Si-N	=BC 818:		35a(2mm)	SOT-323			2SC4097, 2SC4118, 2SD1820(A), 2SD1949
BC 827	Sie	Si-P	LF Drv,Out, 30/25V, 0,8A, 0,8W, 100MHz	BC837	7a	TO-92	BC 327	7a	BC 327…328, BC 636, BC 638, 2SB1116,++
BC 828	Sie	Si-P	=BC 827: 50/45V	BC838	7a	TO-92	BC 327	7a	BC 327, BC 638, BC 640, 2SB1116,++
BC 837	Sie	Si-N	LF Drv,Out, 30/25V, 0,8A, 0,8W, 100MHz	BC827	7a	TO-92	BC 337	7a	BC 337…337, BC 635, BC 637, 2SD1616,++
BC 838	Sie	Si-N	=BC 837: 50/45V	BC828	7a	TO-92	BC 337	7a	BC 337, BC 637, BC 639, 2SD1616,++
BC 846	Phi,Sie,++	Si-N	=BC 546: SMD	BC856	35a	SOT-23	BC 846	35a	BCV 71…72, 2SC1622A, 2SC3324, 2SC4050
BC 846 R		Si-N	=BC 846:		35d	SOT-23			BCV 71R…72R
BC 847	Phi,Sie,++	Si-N	=BC 547: SMD	BC857	35a	SOT-23	BC 846	35a	BCW 71…72, BCW 81, 2SC3323…24,++
BC 847 R		Si-N	=BC 847:		35d	SOT-23			BCW 71R…72R, BCW 81R
BC 848	Phi,Sie,++	Si-N	=BC 548: SMD	BC858	35a	SOT-23	BC 846	35a	BCW 31…33, BCW 71…72, BCW 81, 2SC1622+
BC 848 R		Si-N	=BC 848:		35d	SOT-23			BCW 31R…33R, BCW 71R…72R, BCW 81R
BC 849	Phi,Sie,++	Si-N	=BC 549: SMD	BC859	35a	SOT-23	BC 850	35a	BCF 32…33, BCF 81, 2SC3323…24
BC 849 R		Si-N	=BC 849:		35d	SOT-23			BCF 32R…33R, BCF 81R
BC 850	Phi,Sie,++	Si-N	=BC 550: SMD	BC860	35a	SOT-23	BC 850	35a	BCF 81, 2SC3323…24
BC 850 R		Si-N	=BC 850:		35d	SOT-23			BCF 81R
BC 846-W…850-W	Phi	Si-N	=BC 846…850:		35a(2mm)	SOT-323			2SC4101…02, 2SC4117
BC 856	Phi,Sie,++	Si-P	=BC 556: SMD	BC846	35a	SOT-23	BC 856	35a	BCW 89, 2SA1312, 2SA1566
BC 856 R		Si-P	=BC 856:		35d	SOT-23			BCW 89R
BC 857	Phi,Sie,++	Si-P	=BC 557: SMD	BC847	35a	SOT-23	BC 856	35a	BCW 69…70, BCW 89, 2SA1311…1312,++
BC 857 R		Si-P	=BC 857:		35d	SOT-23			BCW 69R…70R, BCW 89R
BC 858	Phi,Sie,++	Si-P	=BC 558: SMD	BC848	35a	SOT-23	BC 856	35a	BCW 29…30, BCW 69…70, BCW 89, 2SA1311+
BC 858 R		Si-P	=BC 858:		35d	SOT-23			BCW 29R…30R, BCW 69R…70R, BCW 89R
BC 859	Phi,Sie,++	Si-P	=BC 559: SMD	BC849	35a	SOT-23	BC 860	35a	BCF 29…30, BCF 70, 2SA1311…12
BC 859 R		Si-P	=BC 859:		35d	SOT-23			BCF 29R…30R, BCF 70R
BC 860	Phi,Sie,++	Si-P	=BC 560: SMD	BC850	35a	SOT-23	BC 860	35a	BCF 70, 2SA1311…12
BC 860 R		Si-P	=BC 860:		35d	SOT-23			BCF 70R
BC 856-W…860-W	Phi	Si-P	=BC 856…860:		35a(2mm)	SOT-323			2SA1587, 2SA1587
BC 868	Phi	Si-N	=BC 368: SMD	BC869	39b	SOT-89			BCX 54…55, BCX 68, 2SC3444, 2SD1622,++
BC 869	Phi	Si-P	=BC 369: SMD	BC868	39b	SOT-89			BCX 51…52, BCX 69, 2SA1364, 2SB1122,++
BC 875	Phi,Sie	Si-N-Darl+Di	LF,S, 60/45V, 1/2A, 0,8W, 200MHz, hFE>2000	BC876	7c	TO-92	BC 879	7c	BC 618, BSR 50…52, 2SD1853, 2SD1660,++
BC 876	Phi,Sie	Si-P-Darl+Di	LF,S, 60/45V, 1/2A, 0,8W, 200MHz, hFE>2000	BC875	7c	TO-92	BC 880	7c	BSR 60…62, 2SB1129, 2SB1406
BC 877	Phi,Sie	Si-N-Darl+Di	=BC 875: 80/60V	BC878	7c	TO-92	BC 879	7c	BC 618, BSR 51…52, 2SD1853, 2SD1660
BC 878	Phi,Sie	Si-P-Darl+Di	=BC 876: 80/60V	BC877	7c	TO-92	BC 880	7c	BSR 61…62, 2SB1129, 2SB1406
BC 879	Phi,Sie	Si-N-Darl+Di	=BC 875: 100/80V	BC880	7c	TO-92	BC 879	7c	BSR 52, 2SD1660, 2SD2067
BC 880	Phi,Sie	Si-P-Darl+Di	=BC 876: 100/80V	BC879	7c	TO-92	BC 880	7c	BSR 62, 2SB1256, 2SB1387
BCF									
BCF 29	Phi	Si-P	SMD, LF Inp In, 32/32V, 0,1/0,2A, 150MHz hFE=120…260, F<4dB(1kHz)	BCF32	35a	SOT-23	BC 860	35a	BC 859…860, BCF 70, 2SA1311…12
BCF 29 R		Si-P	=BCF 29:		35d	SOT-23			BC 859R…860R, BCF 70R
BCF 30	Phi	Si-P	=BCF 29: hFE=215…500	BCF33	35a	SOT-23	BC 860	35a	BC 859…860, BCF 70, 2SA1311…12
BCF 30 R		Si-P	=BCF 30:		35d	SOT-23			BC 859R…860R, BCF 70R
BCF 32	Phi	Si-N	SMD, LF Inp In, 32/32V, 0,1/0,2A, 300MHz hFE=200…450, F<4dB(1kHz)	BCF29	35a	SOT-23	BC 850	35a	BC 849…850, BCF 81, 2SC3323…24
BCF 32 R		Si-N	=BCF 32:		35d	SOT-23			BC 849R…850R, BCF 81R
BCF 33	Phi	Si-N	=BCF 32: hFE=420…800		35a	SOT-23	BC 850	35a	BC 849…850, BCF 81, 2SC3323…24
BCF 33 R		Si-N	=BCF 33:		35d	SOT-23			BC 849R…850R, BCF 81R

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BCF 70	Phi	Si-P	=BCF 30: 50/45V, hFE=215…500	{BCF81	35a	SOT-23	BC 860	35a	BC 860, 2SA1311…12
BCF 70 R		Si-P	=BCF 70:		35d	SOT-23			BC 860R
BCF 81	Phi	Si-N	=BCF 33: 50/45V, hFE=420…800	{BCF70	35a	SOT-23	BC 850	35a	BC 850, 2SC3323…24
BCF 81 R		Si-N	=BCF 81:		35d	SOT-23			BC 850R
BCP									
BCP		Si-P	=2SB1188-P (SMD-Marking)		39	SOT-89			›2SB1188
BCP 28	Sie	Si-P-Darl	=BCV 26: 1,5W	{BCP29	=39°j	SOT-223			-
BCP 29	Sie	Si-N-Darl	=BCV 27: 1,5W	{BCP28	=39°j	SOT-223			-
BCP 48	Sie	Si-P-Darl	=BCV 46: 1,5W	{BCP49	=39°j	SOT-223			-
BCP 49	Sie	Si-N-Darl	=BCV 47: 1,5W	{BCP48	=39°j	SOT-223			-
BCP 51	Phi,Sie	Si-P	=BCX 51: 1,5W	{BCP54	=39°j	SOT-223			-
BCP 52	Phi,Sie	Si-P	=BCX 52: 1,5W	{BCP55	=39°j	SOT-223			-
BCP 53	Phi,Sie	Si-P	=BCX 53: 1,5W	{BCP56	=39°j	SOT-223			-
BCP 54	Phi,Sie	Si-N	=BCX 54: 1,5W	{BCP51	=39°j	SOT-223			-
BCP 55	Phi,Sie	Si-N	=BCX 55: 1,5W	{BCP52	=39°j	SOT-223			-
BCP 56	Phi,Sie	Si-N	=BCX 56: 1,5W	{BCP53	=39°j	SOT-223			-
BCP 68	Phi,Sie	Si-N	=BCX 68: 1,5W	{BCP69	=39°j	SOT-223			-
BCP 69	Phi,Sie	Si-P	=BCX 69: 1,5W	{BCP68	=39°j	SOT-223			-
BCQ		Si-P	=2SB1188-Q (SMD-Marking)		39	SOT-89			›2SB1188
BCR									
BCR		Si-P	=2SB1188-R (SMD-Marking)		39	SOT-89			›2SB1188
BCR 1 AM-10	Mit	Triac	500V, 1A(Tc=56°), Igt<10mA		7p				ZO 104, ZO 101, ZO 106, TAG 204, TAG 205
BCR 1 AM-12	Mit	Triac	600V, 1A(Tc=56°), Igt<10mA		7p				ZO 104, ZO 101, ZO 106, TAG 204, TAG 205
BCR 1 AM-4	Mit	Triac	200V, 1A(Tc=56°), Igt<10mA		7p				ZO 104, ZO 101, ZO 106, TAG 204, TAG 205
BCR 1 AM-6	Mit	Triac	300V, 1A(Tc=56°), Igt<10mA		7p				ZO 104, ZO 101, ZO 106, TAG 204, TAG 205
BCR 1 AM-8	Mit	Triac	400V, 1A(Tc=56°), Igt<10mA		7p				ZO 104, ZO 101, ZO 106, TAG 204, TAG 205
BCR 3 AM-10	Mit	Triac	500V, 3A(Tc=71°), Igt<30mA		13j		(TAG 232-600)[4]	17j	T 2323, ZO 410, T 2322, ZO 409
BCR 3 AM-12	Mit	Triac	600V, 3A(Tc=71°), Igt<30mA		13j		(TAG 232-600)[4]	17j	T 2323, ZO 410, T 2322, ZO 409
BCR 3 AM-4	Mit	Triac	200V, 3A(Tc=71°), Igt<30mA		13j		(TAG 232-600)[4]	17j	T 2323, ZO 410, T 2322, ZO 409
BCR 3 AM-8	Mit	Triac	400V, 3A(Tc=71°), Igt<30mA		13j		(TAG 232-600)[4]	17j	T 2323, ZO 410, T 2322, ZO 409
BCR 6 AM-10	Mit	Triac	500V, 6A(Tc=103°), Igt<30mA		17j	TO-220	(TAG 232-600)[7]	17j	TAG 220, TAG 225, TAG 252, TAG 250
BCR 6 AM-12	Mit	Triac	600V, 6A(Tc=103°), Igt<30mA		17j	TO-220	(TAG 232-600)[7]	17j	TAG 220, TAG 225, TAG 252, TAG 250
BCR 6 AM-4	Mit	Triac	200V, 6A(Tc=103°), Igt<30mA		17j	TO-220	(TAG 232-600)[7]	17j	TAG 220, TAG 225, TAG 252, TAG 250
BCR 6 AM-6	Mit	Triac	300V, 6A(Tc=103°), Igt<30mA		17j	TO-220	(TAG 232-600)[7]	17j	TAG 220, TAG 225, TAG 252, TAG 250
BCR 6 AM-8	Mit	Triac	400V, 6A(Tc=103°), Igt<30mA		17j	TO-220	(TAG 232-600)[7]	17j	TAG 220, TAG 225, TAG 252, TAG 250
BCR 8 A-10	Mit	Triac	500V, 8A(Tc=92°), Igt<50mA		22q				MAC 222, TIC 226, T 2802, BS 9-A
BCR 8 A-4	Mit	Triac	200V, 8A(Tc=92°), Igt<50mA		22q				MAC 222, TIC 226, T 2802, BS 9-A
BCR 8 A-6	Mit	Triac	300V, 8A(Tc=92°), Igt<50mA		22q				MAC 222, TIC 226, T 2802, BS 9-A
BCR 8 A-8	Mit	Triac	400V, 8A(Tc=92°), Igt<50mA		22q				MAC 222, TIC 226, T 2802, BS 9-A
BCR 8CM-10	Mit	Triac	500V, 8A(Tc=105°), Igt<30mA		17j	TO-220			BTA 21, BT 158, T 2806, BT 162
BCR 8CM-12	Mit	Triac	600V, 8A(Tc=105°), Igt<30mA		17j	TO-220			BTA 21, BT 158, T 2806, BT 162
BCR 8CM-12	Mit	Triac	600V, 8A(Tc=105°), Igt<30mA		17j	TO-220			BTA 21, BT 158, T 2806, BT 162
BCR 8CM-4	Mit	Triac	200V, 8A(Tc=105°), Igt<30mA		17j	TO-220			BTA 21, BT 158, T 2806, BT 162
BCR 8CM-6	Mit	Triac	300V, 8A(Tc=105°), Igt<30mA		17j	TO-220			BTA 21, BT 158, T 2806, BT 162
BCR 8CM-8	Mit	Triac	400V, 8A(Tc=105°), Igt<30mA		17j	TO-220			BTA 21, BT 158, T 2806, BT 162
BCR 8DM-…	Mit	Triac	=BCR 8CM-…: 8A(Tc=94°)		17j	TO-220			BTA 21, BT 158, T 2806, BT 162
BCR 10A-2	Mit	Triac	100V, 10A(Tc=75°), Igt<50mA		76j				-
BCR 10A-4	Mit	Triac	200V, 10A(Tc=75°), Igt<50mA		76j				-
BCR 10A-6	Mit	Triac	300V, 10A(Tc=75°), Igt<50mA		76j				-
BCR 10A-8	Mit	Triac	400V, 10A(Tc=75°), Igt<50mA		76j				-
BCR 10AM-10	Mit	Triac	500V, 10A(Tc=100°), Igt<30mA		17j	TO-220			TAG 252, TAG 257
BCR 10AM-12	Mit	Triac	600V, 10A(Tc=100°), Igt<30mA		17j	TO-220			TAG 252, TAG 257
BCR 10AM-4	Mit	Triac	200V, 10A(Tc=100°), Igt<30mA		17j	TO-220			TAG 252, TAG 257
BCR 10AM-6	Mit	Triac	300V, 10A(Tc=100°), Igt<30mA		17j	TO-220			TAG 252, TAG 257
BCR 10AM-8	Mit	Triac	400V, 10A(Tc=100°), Igt<30mA		17j	TO-220			TAG 252, TAG 257
BCR 10B-2…-8	Mit	Triac	=BCR 10A-2…-8:		=22				-
BCR 10C-2…-8	Mit	Triac	=BCR 10A-2…-8:		21j				SC 245, BS 10-…A, TXD 99, SC 250
BCR 10CM-4…-12	Mit	Triac	=BCR 10AM 4…-12: 10A(Tc=103°)		17j	TO-220			TAG 252, TAG 257
BCR 10DM-4…-12	Mit	Triac	=BCR 10AM 4…-12: 10A(Tc=93°)		17j	TO-220			TAG 252, TAG 257
BCR 10EM-4…-12	Mit	Triac	=BCR 10AM 4…-12: 10A(Tc=80°)		17j	TO-220			TAG 252, TAG 257
BCR 12AM-10	Mit	Triac	500V, 12A(Tc=101°), Igt<30mA		17j	TO-220			TAG 257
BCR 12AM-12	Mit	Triac	600V, 12A(Tc=101°), Igt<30mA		17j	TO-220			TAG 257
BCR 12AM-4	Mit	Triac	200V, 12A(Tc=101°), Igt<30mA		17j	TO-220			TAG 257
BCR 12AM-6	Mit	Triac	300V, 12A(Tc=101°), Igt<30mA		17j	TO-220			TAG 257
BCR 12AM-8	Mit	Triac	400V, 12A(Tc=101°), Igt<30mA		17j	TO-220			TAG 257
BCR 12CM-4…-12	Mit	Triac	=BCR 12AM 4…-12: 12A(Tc=98°)		17j	TO-220			TAG 257
BCR 12DM-4…-12	Mit	Triac	=BCR 12AM 4…-12: 12A(Tc=84°)		17j	TO-220			TAG 257
BCR 12EM-4…-12	Mit	Triac	=BCR 12AM 4…-12: 12A(Tc=77°)		17j	TO-220			TAG 257
BCR 16A-10	Mit	Triac	500V, 16A(Tc=99°), Igt<30mA		76j				-
BCR 16A-4	Mit	Triac	200V, 16A(Tc=99°), Igt<30mA		76j				-
BCR 16A-6	Mit	Triac	300V, 16A(Tc=99°), Igt<30mA		76j				-
BCR 16A-8	Mit	Triac	400V, 16A(Tc=99°), Igt<30mA		76j				-
BCR 16AM-4…-10	Mit	Triac	=BCR 16A-4…-10:						-
BCR 16B-4…-10	Mit	Triac	=BCR 16A-4…-10:		=22				-
BCR 16BM-4…-10	Mit	Triac	=BCR 16A-4…-10:						-
BCR 16C-4…-10	Mit	Triac	=BCR 16A-4…-10:		21j				-
BCR 16CM-12	Mit	Triac	=BCR 16A-4…-10: 600V		17j	TO-220			-
BCR 16CM-4…-10	Mit	Triac	=BCR 16A-4…-10:		17j	TO-220			-
BCR 16DM-12	Mit	Triac	=BCR 16A-4…-10: 600V, 16A(Tc=79°)		17j	TO-220			-
BCR 16DM-4…-10	Mit	Triac	=BCR 16A-4…-10: 16A(Tc=79°)		17j	TO-220			-
BCR 16E-4…-10	Mit	Triac	=BCR 16A-4…-10:		=22				-
BCR 16EM-4…-10	Mit	Triac	=BCR 16A-4…-10: 16A(Tc=73°)						-
BCR 16FM-4…-10	Mit	Triac	=BCR 16A-4…-10: 16A(Tc=73°)						-
BCR 16GM-4…-10	Mit	Triac	=BCR 16A-4…-10: 16A(Tc=73°)						-
BCR 16HM-4…-10	Mit	Triac	=BCR 16A-4…-10: 16A(Tc=82°)		65l				-
BCR 20A-10	Mit	Triac	500V, 20A(Tc=98°), Igt<30mA		76j				-
BCR 20A-4	Mit	Triac	200V, 20A(Tc=98°), Igt<30mA		76j				-
BCR 20A-6	Mit	Triac	300V, 20A(Tc=98°), Igt<30mA		76j				-
BCR 20A-8	Mit	Triac	400V, 20A(Tc=98°), Igt<30mA		76j				-
BCR 20B-4…-10	Mit	Triac	=BCR 20A-4…-10:		=22				-
BCR 20C-4…-10	Mit	Triac	=BCR 20A-4…-10:		21j				-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BCR 20E-4...-10	Mit	Triac	=BCR 20A-4...-10:		=22				-
BCR 25A-10	Mit	Triac	500V, 25A(Tc=92°), Igt<75mA		21j				-
BCR 25A-4	Mit	Triac	200V, 25A(Tc=92°), Igt<75mA		21j				-
BCR 25A-6	Mit	Triac	300V, 25A(Tc=92°), Igt<75mA		21j				-
BCR 25A-8	Mit	Triac	400V, 25A(Tc=92°), Igt<75mA		21j				-
BCR 25B-4...-10	Mit	Triac	=BCR 25A-4...-10:		=22				-
BCR 30GM-10	Mit	Triac	500V, 30A(Tc=60°), Igt<50mA		65l				-
BCR 30GM-4	Mit	Triac	200V, 30A(Tc=60°), Igt<50mA		65l				-
BCR 30GM-6	Mit	Triac	300V, 30A(Tc=60°), Igt<50mA		65l				-
BCR 30GM-8	Mit	Triac	400V, 30A(Tc=60°), Igt<50mA		65l				-
BCR 108	Sie	Si-N+R	SMD, 50V, 0,1A, Rb=2,2kΩ, Rbe=47kΩ		35a	SOT-23			-
BCR 112	Sie	Si-N+R	SMD, 50V, 0,1A, Rb=4,7kΩ, Rbe=4,7kΩ		35a	SOT-23			KSR 1101, 2SC4362
BCR 119	Sie	Si-N+R	SMD, 50V, 0,1A, Rb=4,7kΩ, Rbe=0		35a	SOT-23			KSR 1109, 2SC3900
BCR 133	Sie	Si-N+R	SMD, 50V, 0,1A, Rb=10kΩ, Rbe=10kΩ		35a	SOT-23			KSR 1102, 2SC3398
BCR 135	Sie	Si-N+R	SMD, 50V, 0,1A, Rb=10kΩ, Rbe=47kΩ		35a	SOT-23			KSR 1106, 2SC4047
BCR 141	Sie	Si-N+R	SMD, 50V, 0,1A, Rb=22kΩ, Rbe=22kΩ		35a	SOT-23			KSR 1103, 2SC3396
BCR 142	Sie	Si-N+R	SMD, 50V, 0,1A, Rb=22kΩ, Rbe=47kΩ		35a	SOT-23			KSR 1107
BCR 146	Sie	Si-N+R	SMD, 50V, 0,1A, Rb=47kΩ, Rbe=22kΩ		35a	SOT-23			KSR 1108, 2SC3397
BCR 148	Sie	Si-N+R	SMD, 50V, 0,1A, Rb=47kΩ, Rbe=47kΩ		35a	SOT-23			KSR 1104, 2SC3395
BCR 183	Sie	Si-P+R	SMD, 50V, 0,1A, Rb=10kΩ, Rbe=10kΩ		35a	SOT-23			KSR 2102, 2SA1344
BCR 185	Sie	Si-P+R	SMD, 50V, 0,1A, Rb=10kΩ, Rbe=47kΩ		35a	SOT-23			KSR 2106, 2SA1563
BCR 191	Sie	Si-P+R	SMD, 50V, 0,1A, Rb=22kΩ, Rbe=22kΩ		35a	SOT-23			KSR 2103, 2SA1342
BCR 192	Sie	Si-P+R	SMD, 50V, 0,1A, Rb=22kΩ, Rbe=47kΩ		35a	SOT-23			KSR 2107
BCR 198	Sie	Si-P+R	SMD, 50V, 0,1A, Rb=47kΩ, Rbe=47kΩ		35a	SOT-23			KSR 2104, 2SA1341
BCV									
BCV 26	Phi,Sie,Sgs	Si-P-Darl	SMD, 40/30V, 0,5/0,8A, 200MHz, hFE>20k	{BCV27	35a	SOT-23			BCV 46
BCV 27	Phi,Sie,Sgs	Si-N-Darl	SMD, 40/30V, 0,5/0,8A, 200MHz, hFE>20k	{BCV26	35a	SOT-23			BCV 47
BCV 28	Phi,Sie	Si-P-Darl	=BCV 26:	{BCV29	39b	SOT-89			BST 60...62, 2SB1048
BCV 29	Phi,Sie	Si-N-Darl	=BCV 27:	{BCV28	39b	SOT-89			BST 50...52, 2SD1470, 2SD1511
BCV 46	Phi,Sie,Sgs	Si-P-Darl	=BCV 26: 80/60V	{BCV47	35a	SOT-23			-
BCV 47	Phi,Sie,Sgs	Si-N-Darl	=BCV 27: 80/80V	{BCV46	35a	SOT-23			-
BCV 48	Phi,Sie	Si-P-Darl	=BCV 46:		39b	SOT-89			BST 61...62, 2SB1125...26
BCV 49	Phi,Sie	Si-N-Darl	=BCV 47:	{BCV48	39b	SOT-89			BST 51...52, 2SD1625...26, 2SD1511
BCV 61	Phi,Sie	Si-N	SMD, temp.-komp., 50/30V, 0,1/0,2A, 300MHz	{BCV62	44	SOT-143			-
BCV 62	Phi,Sie	Si-P	SMD, temp.-komp., 50/30V, 0,1/0,2A, 150MHz	{BCV61	44	SOT-143			-
BCV 63	Phi	Si-N	SMD, Schmitt-Trigger, =Darl, 30/6V, 0,1A	{BCV64	44p	SOT-143			-
BCV 64	Phi	Si-P	SMD, Schmitt-Trigger, =Darl, 30/6V, 0,1A	{BCV63	44p	SOT-143			-
BCV 65	Phi	Si-P+N	SMD, = BC 557+BC 547		44(EECBBC)	SOT-143			-
BCV 71	Fer,Phi,Sgs	Si-N	LF,S, 80/60V, 0,1/0,2A, 300MHz, hFE=110...220		35a	SOT-23	BC 846	35a	BC 846, 2SC1622A, 2SC3324, 2SC4050
BCV 71 R		Si-N	=BCV 71:		35d	SOT-23			BC 846R, 2SC3340
BCV 72	Fer,Phi,Sgs	Si-N	=BCV 71: hFE=200...450		35a	SOT-23	BC 846	35a	BC 846, 2SC1622A, 2SC3324, 2SC4050
BCV 72 R		Si-N	=BCV 72:		35d	SOT-23			BC 846R, 2SC3340
BCW									
BCW 10	Fer	Si-N	LF, 25/25V, -/0,5A, 0,3W, >150MHz	{BCW11	40e	=TO-92	BC 337	7a	BC 337...338, BC 635, BC 637, 2SC3377,++
BCW 11	Fer	Si-P	LF, 25/25V, -/0,5A, 0,3W, >150MHz	{BCW10	40e	=TO-92	BC 327	7a	BC 327...328, BC 636, BC 638, 2SA1515,++
BCW 12	Fer	Si-N	=BCW 10: 35/35V	{BCW13	40e	=TO-92	BC 337	7a	BC 337, BC 635, BC 637, 2SC3377,++
BCW 13	Fer	Si-P	=BCW 11: 35/35V	{BCW12	40e	=TO-92	BC 327	7a	BC 327, BC 636, BC 638, 2SA1515,++
BCW 14	Fer	Si-N	=BCW 10: 35/35V	{BCW15	40e	=TO-92	BC 337	7a	BC 337, BC 635, BC 637, 2SC3377,++
BCW 15	Fer	Si-P	=BCW 11: 35/35V	{BCW14	40e	=TO-92	BC 327	7a	BC 327, BC 636, BC 638, 2SA1515,++
BCW 16	Fer	Si-N	=BCW 10: 45/45V	{BCW17	40e	=TO-92	BC 337	7a	BC 337, BC 635, BC 637, 2SC3939,++
BCW 17	Fer	Si-P	=BCW 11: 45/45V	{BCW16	40e	=TO-92	BC 327	7a	BC 327, BC 636, BC 638, 2SA1533,++
BCW 18	Fer	Si-N	=BCW 10: 70/70V	{BCW19	40e	=TO-92	BC 639	7c	BC 639, 2SC2235, 2SC3939, 2SD1226,++
BCW 19	Fer	Si-P	=BCW 11: 70/70V	{BCW18	40e	=TO-92	BC 640	7c	BC 640, 2SA965, 2SA1533, 2SB910,++
BCW 20	Fer	Si-N	LF In, 30/30V, -/0,5A, 0,3W, >30MHz, F<3dB	{BCW21	40e	=TO-92	BC 550	7a	BC 109, BC 184, BC 239, BC 549, 2SC2675+
BCW 21	Fer	Si-P	LF In, 30/30V, -/0,5A, 0,3W, >30MHz, F<3dB	{BCW20	40e	=TO-92	BC 560	7a	BC 214, BC 259, BC 309, BC 559, 2SA1137+
BCW 22	Fer	Si-N	=BCW 20: 45/45V	{BCW23	40e	=TO-92	BC 550	7a	BC 184, BC 413...414, BC 550, 2SC2675,++
BCW 23	Fer	Si-P	=BCW 20: 45/45V	{BCW22	40e	=TO-92	BC 560	7a	BC 214, BC 415...416, BC 560, 2SA1137,++
BCW 24	Itt	Si-N	LF In, 45/45V, 30mA, 0,3W, >30MHz, F<3dB(1kHz)		2a	TO-18	BC 550	7a	BC 184, BC 413...414, BC 550, 2SC2675,++
BCW 25	Tix	Si-N	Dual, 60/50V, 0,5A, 50MHz		TO-99	(CBE-EBC-)			2N2060(A), 2N2223(A)
BCW 26	Tix	Si-N	=2x BCW 25 Matched Pair		TO-99	(CBE-EBC-)			2N2060(A), 2N2223(A)
BCW 27	Tix	Si-P	Uni, 150V, 0,1A, 0,625W		7d	SOT-30			BF 422, BF 398, BF 435...437, 2SA1019, ++
BCW 28	Tix	Si-P	Uni, 100V, 0,1A, 0,625W		7d	SOT-30			BF 422, BF 398, BF 435...437, 2SA1019, ++
BCW 29	Phi,Sgs,++	Si-P	SMD, Uni, 30/20V, 0,1/0,2A, 150MHz, hFE=120...250	{BCW31	35a	SOT-23	BC 856	35a	BC856...858, BCW69...70, BCW89, 2SA1311,++
BCW 29 R		Si-P	=BCW 29:		35d	SOT-23			BC 856R...858R, BCW 69R...70R, BCW 89R, ++
BCW 30	Phi,Sgs,++	Si-P	=BCW 29: hFE=215...500		35a	SOT-23	BC 856	35a	BC856...858, BCW69...70, BCW89, 2SA1311,++
BCW 30 R		Si-P	=BCW 30:		35d	SOT-23			BC 856R...858R, BCW 69R...70R, BCW 89R, ++
BCW 31	Phi,Sgs,++	Si-N	SMD, Uni, 30/20V, 0,1/0,2A, 300MHz, hFE=110...220	{BCW29	35a	SOT-23	BC 846	35a	BC846...848, BCW71...72, BCW81, 2SC3323,++
BCW 31 R		Si-N	=BCW 31:		35d	SOT-23			BC 846R...848R, BCW 71R...72R, BCW 81R, ++
BCW 32	Phi,Sgs,++	Si-N	=BCW 31: hFE=200...450		35a	SOT-23	BC 846	35a	BC846...848, BCW71...72, BCW81, 2SC3323,++
BCW 32 R		Si-N	=BCW 32:		35d	SOT-23			BC 846R. .848R, BCW 71R...72R, BCW 81R, ++
BCW 33	Phi,Sgs,++	Si-N	=BCW 31: hFE=420...800		35a	SOT-23	BC 846	35a	BC846...848, BCW71...72, BCW81, 2SC3323,++
BCW 33 R		Si-N	=BCW 33:		35d	SOT-23			BC 846R...848R, BCW 71R...72R, BCW 81R, ++
BCW 34	Tix	Si-N	LF Drv, 60/45V, 0,6A, 0,36W, >150MHz	{BCW35	2a	TO-18			BC 637, BC 639, BCX 22, BCX 24, 2SD1616+
BCW 35	Tix	Si-P	LF Drv, 60/45V, 0,6A, 0,36W, >150MHz	{BCW34	2a	TO-18			BC 638, BC 640, BCX 23, BCX 39, 2SB1116+
BCW 36	Tix	Si-N	=BCW 34: 0,3W		7a	TO-92			›BCW 34
BCW 37	Tix	Si-P	=BCW 35: 0,3W		7a	TO-92			›BCW 35
BCW 38	Tix	Si-N	LF Drv, 60/40V, 0,6A, 0,625W, >200MHz, hFE>40		7a	SOT-30			BC 637, BC 639, 2SC4485, 2SD1616(A),++
BCW 39	Tix	Si-N	=BCW 38: >250MHz, hFE>80		7a	SOT-30			BC 637, BC 639, 2SC4485, 2SD1616(A),++
BCW 44	Sgs	Si-N	LF Drv, 70/55V, 1A, 0,8W, 80MHz	{BCW45	2a	TO-39			BC 140...141, BCX 40, 2N1990, 2N2102, ++
BCW 45	Sgs	Si-P	LF Drv, 70/55V, 1A, 0,8W, 200MHz	{BCW44	2a	TO-39			BC 161, BCX 60, 2N4235...4236, ++
BCW 46	Phi	Si-N	=BCW 48: 80/60V	{BCW56	12a	SOT-33	BC 546	7a	BC174, BC190, BC546, 2SC1890, 2SC2675,++
BCW 47	Phi	Si-N	=BCW 48: 50/45V	{BCW57	12a	SOT-33	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BCW 48	Phi	Si-N	Uni, 30/20V, 0,1/0,2A, 0,2W, 300MHz	{BCW58	12a	SOT-33	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BCW 49	Phi	Si-N	=BCW 48: In, F<4dB(1kHz)	{BCW59	12a	SOT-33	BC 550	7a	BC 169, BC 184, BC 239, BC 549, 2SC2675+
BCW 50	Sgs	Si-N	LF, 120/120V, 0,5W, >50MHz		2a	TO-18	2SC2632	7c(9mm)	2SC1890A, 2SC2240, 2SC2631...32, 2SC3378+
BCW 51	Tix	Si-N	LF,S, 50/30V, 0,2A, 0,3W, >200MHz	{BCW52	7a	SOT-30			BC 167, BC 182, BC 237, BC 547, 2SD767++
BCW 52	Tix	Si-P	LF,S, 50/30V, 0,2A, 0,3W, >200MHz	{BCW51	7a	SOT-30			BC 212, BC 257, BC 307, BC 557, 2SB725++
BCW 54	Itt	Si-N	LF, 64/64V, 0,1A, 0,3W, 300MHz, hfe=125...260		2a	TO-18			BC174, BC190, BC546, 2SC1890, 2SC2675,++
BCW 55	Itt	Si-N	=BCW 54: hfe=240...500		2a	TO-18			BC174, BC190, BC546, 2SC1890, 2SC2675,++

Original	Fabric.	Constr.	Info	Compl.	Fig.		JAEGER	Fig.	International
BCW 56	Phi	Si-P	=BCW 58: 80/60V	(BCW46	12a	SOT-33	BC 556	7a	BC 556, BC 477, 2SA893, 2SB715, 2SA1137+
BCW 57	Phi	Si-P	=BCW 58: 50/45V	(BCW47	12a	SOT-30	BC 556	7a	BC 212, BC 257, BC 307, BC 557, 2SB725++
BCW 58	Phi	Si-P	Uni, 30/20V, 0,1/0,2A, 0,2W, 150MHz	(BCW48	12a	SOT-33	BC 556	7a	BC 213, BC 258, BC 308, BC 558, 2SB725++
BCW 59	Phi	Si-P	=BCW 58: In, F<4dB(1kHz)	(BCW49	12a	SOT-33	BC 560	7a	BC 214, BC 259, BC 309, BC 559, 2SA1137+
BCW 60	EUR	Si-N	SMD, Uni, 32/32V, 0,2A, 250MHz, 85/480ns	(BCW61	35a	SOT-23	BC 846	35a	BC846...848, BCW31...33, BCX70, 2SC4209,++
BCW 60 R		Si-N	=BCW 60:		35d	SOT-23			BC 846R...848R, BCW 31R...33R, BCX 70R, ++
BCW 61	EUR	Si-P	SMD, Uni, 32/32V, 0,2A, 180MHz, 85/480ns	(BCW60	35a	SOT-23	BC 856	35a	BC856...858, BCW29...30, BCX71, 2SA1620,++
BCW 61 R		Si-P	=BCW 61:		35d	SOT-23			BC 856R...858R, BCW 29R...30R, BCX 71R, ++
BCW 62	Tix	Si-P	=BCW 63: 60V	(BCW82	9c				BC 212, BC 256, BC 266, BC 556, 2SB725++
BCW 63	Tix	Si-P	Uni, 45/30V, 0,2A, 0,225W, >200MHz	(BCW83	9c				BC 213, BC 257, BC 307, BC 557, 2SB725++
BCW 64	Tix	Si-P	=BCW 63: In, F<2dB(1kHz)	(BCW84	9c				BC 214, BC 415...416, BC 560, 2SA1137,++
BCW 65	Sie,Sgs,++	Si-N	SMD, 60/32V, 0,8/1A, >100MHz, <100/400ns	(BCW67	35a	SOT-23			BCX 41, 2SD1782
BCW 65 R		Si-N	=BCW 65:		35d	SOT-23			BCX 41R
BCW 66	Sie,Sgs,++	Si-N	=BCW 65: 75/45V	(BCW68	35a	SOT-23			BCX 41, 2SD1782
BCW 66 R		Si-N	=BCW 66:		35d	SOT-23			BCX 41R
BCW 67	Sie,Sgs,++	Si-P	SMD, 45/32V, 0,8/1A, >100MHz, <100/400ns	(BCW65	35a	SOT-23			BCX 42
BCW 67 R		Si-P	=BCW 67:		35d	SOT-23			BCX 42R
BCW 68	Sie,Sgs,++	Si-P	=BCW 67: 60/45V	(BCW66	35a	SOT-23			BCX 42
BCW 68 R		Si-P	=BCW 68:		35d	SOT-23			BCX 42R
BCW 69	Phi,Sgs,++	Si-P	SMD, Uni, 50/45V, 0,1/0,2A, 150MHz, hFE=120...260	(BCW71	35a	SOT-23	BC 856	35a	BC 856...857, BCW 89, 2SA1311...12,++
BCW 69 R		Si-P	=BCW 69:		35d	SOT-23			BC 856R...857R, BCW 89R
BCW 70	Phi,Sgs,++	Si-P	=BCW 69: hFE=215...500	(BCW72	35a	SOT-23	BC 856	35a	BC 856...857, BCW 89, 2SA1311...12,++
BCW 70 R		Si-P	=BCW 70:		35d	SOT-23			BC 856R...857R, BCW 89R
BCW 71	Phi,Sgs,++	Si-N	SMD, LF, 50/45V, 0,1/0,2A, 300MHz, hFE=110...220	(BCW69	35a	SOT-23	BC 846	35a	BC 846...847, BCV 71...72, 2SC3323...24,++
BCW 71 R		Si-N	=BCW 71:		35d	SOT-23			BC 846R...847R, BCV 71R...72R
BCW 72	Phi,Sgs,++	Si-N	=BCW 71: hFE=200...450	(BCW70	35a	SOT-23	BC 846	35a	BC 846...847, BCV 71...72, 2SC3323...24,++
BCW 72 R		Si-N	=BCW 72:		35d	SOT-23			BC 846R...847R, BCV 71R...72R
BCW 73	Sie	Si-N	Uni,60/32V, 0,8A, 0,45W, >100MHz,<100/400ns	(BCW75	2a	TO-18			BC 637, BC 639, BCX 73, 2N2221...2222, ++
BCW 74	Sie	Si-N	=BCW 73: 75/45V	(BCW76	2a	TO-18			BC 639, BCX 74, 2N2221A...2222A, ++
BCW 75	Sie	Si-P	Uni,45/32V, 0,8A, 0,45W, >100MHz,<100/400ns	(BCW73	2a	TO-18			BC 638, BC 640, BCX 75, 2N2906...2907, ++
BCW 76	Sie	Si-P	=BCW 75: 60/45V	(BCW74	2a	TO-18			BC 640, BCX 76, 2N2906A...2907A, ++
BCW 77	Sie	Si-N	=BCW 73: 0,87W	(BCW79	2a	TO-39			BC 140...141, 2N2218...2219, ++
BCW 78	Sie	Si-N	=BCW 74: 0,87W	(BCW80	2a	TO-39			BC 140...141, 2N2218A...2219A, ++
BCW 79	Sie	Si-P	=BCW 75: 0,87W	(BCW77	2a	TO-39			BC 161, 2N2904...2905, ++
BCW 80	Sie	Si-P	=BCW 76: 0,87W	(BCW78	2a	TO-39			BC 161, 2N2904A...2905A, ++
BCW 81	Phi,Sgs	Si-N	=BCW 71: hFE=420...800		35a	SOT-23	BC 846	35a	BC 846...847, BCV 71...72, 2SC3323...24,++
BCW 81 R		Si-N	=BCW 81:		35d	SOT-23			BC 846R...847R, BCV 71R...72R
BCW 82	Tix	Si-N	=BCW 83: 60/50V	(BCW62	9c				BC 182, BC 174, BC 190, BC 546, 2SD767++
BCW 83	Tix	Si-N	Uni, 45/30V, 0,2A, 0,225W, >150MHz	(BCW63	9c				BC 167, BC 183, BC 237, BC 547, 2SD767++
BCW 84	Tix	Si-N	=BCW 83: In, F<4dB(1kHz)	(BCW64	9c				BC 184, BC 413...414, BC 550, 2SC2675,++
BCW 85	Tix	Si-P	LF,S, 90/60V, 0,2A, 0,3W, >200MHz	(BCY85	7a	SOT-30			BC 477, BC 556, 2SA1049, 2SA1335,++
BCW 86	Tix	Si-P	=BCW 85: 70/50V	(BCY86	7a	SOT-30			BC 477, BC 556, 2SA1137, 2SA1335,++
BCW 87	Sie	Si-N	LF, 45/45V, 0,1A, 0,225W, >125MHz	(BCW88	36e	(1,8x4,5Ø)			BC 167, BC 183, BC 237, BC 547, 2SD767++
BCW 88	Sie	Si-P	LF, 45/45V, 0,1A, 0,225W, >180MHz	(BCW87	36e	(1,8x4,5Ø)			BC 213, BC 257, BC 307, BC 557, 2SB725++
BCW 89	Phi,Sgs,++	Si-P	=BCW 69: 80/60V		35a	SOT-23	BC 856	35a	BC 856, 2SA1312, 2SA1325, 2SA1566
BCW 89 R		Si-P	=BCW 89:		35d	SOT-23			BC 856R
BCW 90	Tho	Si-N	LF Drv, 50/40V, 0,8/1,2A, 0,61W, >135MHz	(BCW92	7a	SOT-30			BC 337, BC 637, BC 639, 2SD1616(A),++
BCW 90 K		Si-N	=BCW 90: Heatsink, 0,8W		7a°	SOT-30			+BCW 90
BCW 91	Tho	Si-N	=BCW 90: 70/60V	(BCW93	7a	SOT-30			BC 639, 2SC4488, 2SD1616A, 2SD2181,++
BCW 91 K		Si-N	=BCW 91: Heatsink, 0,8W		7a°	SOT-30			+BCW 91
BCW 92	Tho	Si-P	LF Drv, 50/40V, 0,8/1,2A, 0,61W, >135MHz	(BCW90	7a	SOT-30			BC 327, BC 638, BC 640, 2SB1116(A),++
BCW 92 K		Si-P	=BCW 92: Heatsink, 0,8W		7a°	SOT-30			+BCW 92
BCW 93	Tho	Si-P	=BCW 92: 70/60V	(BCW91	7a	SOT-30			BC 640, 2SA1708, 2SB1116(A), 2SB1437,++
BCW 93 K		Si-P	=BCW 93: Heatsink, 0,8W		7a°	SOT-30			+BCW 93
BCW 94	Tho	Si-N	LF Drv, 50/40V, 0,4/1A, 0,54W, 70MHz	(BCW96	7a	SOT-30			BC 337, BC 637, BC 639, 2SD1616(A),++
BCW 94 K		Si-N	=BCW 94: Haetsink, 0,7W		7a°	SOT-30			+BCW 94
BCW 95	Tho	Si-N	=BCW 94: 70/60V	(BCW97	7a	SOT-30			BC 639, 2SC3939, 2SD1226, 2SD1616A,++
BCW 95 K		Si-N	=BCW 95: Heatsink, 0,7W		7a°	SOT-30			+BCW 95
BCW 96	Tho	Si-P	LF Drv, 50/40V, 0,4/1A, 0,54W, 70MHz	(BCW94	7a	SOT-30			BC 327, BC 638, BC 640, 2SB1116(A),++
BCW 96 K		Si-P	=BCW 96: Heatsink, 0,7W		7a°	SOT-30			+BCW 96
BCW 97	Tho	Si-P	=BCW 96: 70/60V	(BCW95	7a	SOT-30			BC 640, 2SA1533, 2SB910, 2SB1116A,++
BCW 97 K		Si-P	=BCW 97: Heatsink, 0,7W		7a°	SOT-30			+BCW 97
BCW 98	Aeg	Si-N	Min, 45/45V, 0,1A, 0,05W, >125MHz	(BCW99	9c				BC 123
BCW 99	Aeg	Si-P	Min, 45/45V, 0,1A, 0,05W, 200MHz	(BCW98	9c				BC 203
BCX									
BCX 10	Sgs	Si-P	LF,S, 50/35V, 0,6A, 0,6W, 90MHz (=2N1132)		2a	TO-39			BC 161, BC 303...304, BCX 60, BSV 16...17
BCX 12	Sie	Si-N	LF,S, 125/125V, 0,8/1A, 0,625W, 100MHz	(BCX13	7a	TO-92	2SD1812	7c	2SC4488, 2SD1312, 2SD1616A, 2SD1857, ++
BCX 13	Sie	Si-P	LF,S, 125/125V, 0,8/1A, 0,625W, 120MHz	(BCX12	7a	TO-92	2SB1212	7c	2SA1708, 2SB984, 2SB1236, 2SB1456, ++
BCX 17	Phi,Sgs,++	Si-P	SMD, LF Drv, 50/45V, 0,5/1A, 100MHz	(BCX19	35a	SOT-23	BC 807	35a	BC 807, BCW 68, BCX 42, 2SA1366
BCX 17 R		Si-P	=BCX 17:		35d	SOT-23			BC 807R, BCW 68R, BCX 42R
BCX 18	Phi,Sgs,++	Si-P	=BCX 17: 30/25V	(BCX20	35a	SOT-23	BC 807	35a	BC 807...808, BCW 67...68, 2SA1366
BCX 18 R		Si-P	=BCX 18:		35d	SOT-23			BC 807R...808R, BCW 67R...68R
BCX 19	Phi,Sgs,++	Si-N	SMD, LF Drv 50/45V, 0,5/1A, 200MHz	(BCX17	35a	SOT-23	BC 817	35a	BC 817, BCW 65...66, BCX 41, 2SC3441
BCX 19 R		Si-N	=BCX 19:		35d	SOT-23			BC 817R, BCW 65R...66R, BCX 41R
BCX 20	Phi,Sgs,++	Si-N	=BCX 19: 30/25V	(BCX18	35a	SOT-23	BC 817	35a	BC 817...818, BCW 65...66, 2SC3441
BCX 20 R		Si-N	=BCX 20:		35d	SOT-23			BC 817R...818R, BCW 65R...66R
BCX 21	Phi,Fer	Si-N-Darl	LF,S, 60/45V, 1A, 0,65W, 350MHz, hFE>2000		2a	TO-39			BSS 50...52, 2SD614...615, 2SD688
BCX 22	Phi,Sie	Si-N	LF Inp,Drv, 125/125V, 0,8/1A, 0,45W, 100MHz	(BCX23	2a	TO-18	2SD1812	7c(9mm)	2SC4488, 2SD1616A, 2SD1768, 2SD2181,++
BCX 23	Phi,Sie	Si-P	LF Inp,Drv, 125/125V, 0,8/1A, 0,45W, 100MHz	(BCX22	2a	TO-18	2SB1212	7c(9mm)	2SA1708, 2SB984, 2SB1116A, 2SB1437,++
BCX 24	Sie	Si-N	LF Inp,Drv, -/100V, 0,8/1A, 0,45W, 100MHz	(BCX39	2a	TO-18	2SD1812	7c(9mm)	2SC4488, 2SD1616A, 2SD1768, 2SD2181,++
BCX 25	Mot	Si-N	LF, 60/60V, 0,2A, 0,35W, >100MHz	(BCX26	7a	TO-92			BC 174, BC 182, BC 190, BC 546, 2SD767++
BCX 26	Mot,	Si-P	LF, 60/60V, 0,2A, 0,35W, >100MHz	(BCX25	7a	TO-92			BC 212, BC 256, BC 266, BC 556, 2SB725++
BCX 27	Mot	Si-N	=BCX 25: 80/80V	(BCX28	7a	TO-92			BC 546, 2SC2240, 2SC2459, 2SC2675,++
BCX 28	Mot	Si-P	=BCX 26: 80/80V	(BCX27	7a	TO-92			BC 556, 2SA970, 2SA1049, 2SA1137,++
BCX 29	Mot	Si-N	=BCX 25: 100/100V	(BCX30	7a	TO-92			2SC2240, 2SC2459, 2SC2675, 2SC3378,++
BCX 30	Mot	Si-P	=BCX 26: 100/100V	(BCX29	7a	TO-92			2SA970, 2SA1049, 2SA1137, 2SA1335,++
BCX 31	Phi	Si-N	LF, 100/80V, 0,5/1A, 0,83W, >80MHz		11a	SOT-25			BC 639, 2SC4414, 2SD774, 2SD1616A,++
BCX 32	Phi	Si-N	LF, 80/60V, 1/2A, 0,83W, >80MHz	(BCX35	11a	SOT-25			BC 639, 2SC4488, 2SD1616A, 2SD2181,++
BCX 33	Phi	Si-N	=BCX 32: 60/40V	(BCX36	11a	SOT-25			BC 637, BC 639, 2SC4485, 2SD1616(A),++
BCX 34	Phi	Si-N	=BCX 32: 40/30V	(BCX37	11a	SOT-25			BC 635, BC 637, 2SD1616(A), 2SD1225,++

Original	Fabric.	Constr.	Info	(Compl.	Fig.		JAEGER	Fig.	International
BCX 35	Phi	Si-P	LF, 80/80V, 0,6/1A, 0,83W, >80MHz	(BCX32	11a	SOT-25			BC 640, 2SA1708, 2SB1116A, 2SB1437,++
BCX 36	Phi	Si-P	=BCX 35: 60/60V	(BCX33	11a	SOT-25			BC 638, BC 640, 2SA1705, 2SB1116(A),++
BCX 37	Phi	Si-P	=BCX 35: 40/40V	(BCX34	11a	SOT-25			BC 636, BC 638, 2SB909, 2SB1116(A),++
BCX 38	Fer	Si-N-Darl	LF Drv, 80/60V, 0,8A, 1W, hFE>500		40e	≈TO-92			BC 877, BC 879, BSR 51…52, 2SD2116,++
BCX 39	Sie	Si-P	LF Inp,Drv, 100/100V, 0,8/1A, 0,45W, 100MHz	(BCX24	2a	TO-18			BC 640, 2SA1708, 2SB1116A, 2SB1437,++
BCX 40	Sgs	Si-N	LF Drv,Out, 100/80V, -/2A, 1W, >50MHz	(BCX60	2a	TO-39			BSS 15, 2N4239, 2N5320, 2SC2214
BCX 41	Sie,Tho	Si-N	SMD, LF, 125/125V, 0,8/1A, 100MHz	(BCX42	35a	SOT-23			-
BCX 41 R		Si-N	=BCX 41:		35d	SOT-23			-
BCX 42	Sie,Tho	Si-P	SMD, LF, 125/125V, 0,8/1A, 100MHz	(BCX41	35a	SOT-23			-
BCX 42 R		Si-P	=BCX 42:		35d	SOT-23			-
BCX 43	Tho	MOS-N-FET-e	150/150V, 1A, Idss>0,5mA, Up=0,8…2V		7	TO-92			-
BCX 44	Tho	MOS-N-FET-e	90/90V, 0,5A, Idss<0,01mA, Up=0,8…2V		7	TO-92			-
BCX 45	Mot	Si-N	LF, 45/45V, 1A, 0,625W, >100MHz	(BCX46	7a	TO-92			BC 635, BC 637, 2SC4485, 2SD1616(A),++
BCX 46	Mot	Si-P	LF, 45/45V, 1A, 0,625W, >60MHz	(BCX45	7a	TO-92			BC 636, BC 638, 2SA1705, 2SB1116(A),++
BCX 47	Mot	Si-N	=BCX 45: 60/60V	(BCX48	7a	TO-92			BC 637, BC 639, 2SC4485, 2SD1616(A),++
BCX 48	Mot	Si-P	=BCX 46: 60/60V	(BCX47	7a	TO-92			BC 638, BC 640, 2SA1705, 2SB1116(A),++
BCX 49	Mot	Si-N	=BCX 45: 80/80V	(BCX50	7a	TO-92			BC 639, 2SC4488, 2SD1616A, 2SD2181,++
BCX 50	Mot	Si-P	=BCX 46: 80/80V	(BCX49	7a	TO-92			BC 640, 2SA1708, 2SB1116A, 2SB1437,++
BCX 51	Mot,Phi,Sie	Si-P	SMD, LF Drv, 45/45V, 1/1,5A, 50MHz	(BCX54	39b	SOT-89			2SA1364, 2SB1115(A), 2SB1122…23,++
BCX 52	Mot,Phi,Sie	Si-P	=BCX 51: 60/60V	(BCX55	39b	SOT-89			2SA1364, 2SB1115(A), 2SB1122…23,++
BCX 53	Mot,Phi,Sie	Si-P	=BCX 51: 100/80V	(BCX56	39b	SOT-89			2SA1416, 2SB803…04, 2SB1025…26,++
BCX 54	Mot,Phi,Sie	Si-N	SMD, LF Drv, 45/45V, 1/1,5A, 130MHz	(BCX51	39b	SOT-89			2SC3444, 2SC4409, 2SD1615, 2SD1622…23++
BCX 55	Mot,Phi,Sie	Si-N	=BCX 54: 60/60V	(BCX52	39b	SOT-89			2SC3444, 2SC4409, 2SD1615, 2SD1622…23++
BCX 56	Mot,Phi,Sie	Si-N	=BCX 54: 100/80V	(BCX53	39b	SOT-89			2SD1005, 2SD1368, 2SD1418…19, 2SD1422++
BCX 58	Phi,Sie,++	Si-N	LF,S, 32/32V, 0,1/0,2A, 0,45W, 250MHz, 55/450ns	(BCX78	7a	TO-92			BC 183, BC 237, BC 547, 2N2221…2222, ++
BCX 59	Phi,Sie,++	Si-N	=BCX 58: 45/45V	(BCX79	7a	TO-92			BC 182, BC 237, BC 547, 2N2221…2222, ++
BCX 60	Sgs	Si-P	LF Drv,Out, 100/80V, -/2A, 1W, >50MHz	(BCX40	2a	TO-39			BSS 17, 2N5322
BCX 68	Mot,Phi,Sie	Si-N	SMD, Uni, 25/20V, 1/2A, 65MHz	(BCX69	39b	SOT-89			BC 868, BCX 54…56, 2SC3444, 2SC4539,++
BCX 69	Mot,Phi,Sie	Si-P	SMD, Uni, 25/20V, 1/2A, 65MHz	(BCX68	39b	SOT-89			BC 869, BCX 51…53, 2SA1364, 2SA1734,++
BCX 70	EUR	Si-N	=BCW 60: 45/45V	(BCX71	35a	SOT-23	BC 846	35a	BC846…847, BCW71…72, BCW81, 2SC4209,++
BCX 70 R		Si-N	=BCX 70:		35d	SOT-23			BC 846R…847R, BCW 71R…72R, BCW 81R
BCX 71	EUR	Si-P	=BCW 61: 45/45V	(BCX70	35a	SOT-23	BC 856	35a	BC856…857, BCW69…70, BCW89, 2SA1620,++
BCX 71 R		Si-P	=BCX 71:		35d	SOT-23			BC 856R…857R, BCW 69R…70R, BCW 89R
BCX 73	Mot,Sie	Si-N	LF,S, 60/32V, 0,8/1A, 0,625W, >100MHz, <100/400ns	(BCX75	7a	TO-92			BC 637, BC 639, BCX 73, 2N2221…2222,++
BCX 74	Mot,Sie	Si-N	=BCX 73: 75/45V	(BCX76	7a	TO-92			BC 639, BCW 74, 2N2221A…2222A, ++
BCX 75	Mot,Sie	Si-P	LF,S, 60/32V, 0,8/1A, 0,625W, >100MHz, <100/400ns	(BCX73	7a	TO-92			BC 638, BC 640, BCW 75, 2N2906…2907,++
BCX 76	Mot,Sie	Si-P	=BCX 75: 75/45V	(BCX74	7a	TO-92			BC 640, BCW 76, 2N2906A…2907A, ++
BCX 78	Phi,Sie,++	Si-P	LF,S, 32/32V, 0,1/0,2A, 0,45W, 200MHz, 55/450ns	(BCX58	7a	TO-92			BC 213, BC 307, BC 557, 2N2906…2907, ++
BCX 79	Phi,Sie,++	Si-P	=BCX 78: 45/45V	(BCX59	7a	TO-92			BC 213, BC 307, BC 557, 2N2906…2907, ++
BCX 80	Gen	Si-N	LF Drv, 50/40V, 0,75A, 0,5W, >120MHz	(BCX81	7a	SOT-30			BC 337, BC 637, 2SC4485, 2SD1616(A),++
BCX 81	Gen	Si-P	LF Drv, 50/40V, 0,75A, 0,5W, >120MHz	(BCX80	7a	SOT-30			BC 327, BC 638, 2SA1705, 2SB1116(A),++
BCX 82	Gen	Si-N	Uni, In, 100V, 0,1A, >75MHz, hFE=250…800		7a	SOT-30			2SC2240, 2SC2459, 2SC2675, 2SC3378,++
BCX 83	Gen	Si-N	=BCX 82: hFE=600…1200		7a	SOT-30			2SC2240, 2SC2459, 2SC2675, 2SC3378,++
BCX 84	Gen	Si-P	LF Drv, 60/60V, 0,5A, 0,5W, >60MHz	(BCX85	7a	SOT-30			BC 638, BC 640, 2SA1705, 2SB1116(A),++
BCX 85	Gen	Si-N	LF Drv, 60/60V, 0,5A, 0,5W, >80MHz	(BCX84	7a	SOT-30			BC 637, BC 639, 2SC4485, 2SD1616(A),++
BCX 86	Gen	Si-N-Darl	LF, 25/25V, 0,5A, 0,5W, >80MHz, hFE>2000	(BCX87	7a	SOT-30			BC 517, BC 875, BC 877, MPS-A13…14,++
BCX 87	Gen	Si-P-Darl	LF, 25/25V, 0,5A, 0,5W, >80MHz, hFE>2000	(BCX86	7a	SOT-30			BC 516, BC 876, BC 878, MPS-A63…64,++
BCX 88	Gen	Si-N-Darl	=BCX 86: hFE>87000	(BCX89	7a	SOT-30			BC 517, MPS-A14, (BC 875, BC 877)
BCX 89	Gen	Si-P-Darl	=BCX 87: hFE>40000	(BCX88	7a	SOT-30			BC 516, MPS-A64, (BC 876, BC 878)
BCX 94	Sie	Si-N	LF Inp,Drv, 100/100V, 0,8/1A, 0,45W, 100MHz		2a	TO-18			BC 639, 2SC4488, 2SD1616A, 2SD2181,++
BCY									
BCY 10	Phi	Si-P	LF, 32/24/12V, 0,25/0,5A, 0,31W, 1,5MHz, hFE=15		1a	(15x6mmØ)			BC 327, BC 636, BC 638, 2SC3377,++
BCY 11	Phi	Si-P	=BCY 10: 60/24/12V		1a	(15x6mmØ)			BC 638, BC 640, 2N2906A…07A, 2SD1226,++
BCY 12	Phi	Si-P	=BCY 10: 60/24/12V, hFE=25		1a	(15x6mmØ)			BC 638, BC 640, 2N2906A…07A, 2SD1226,++
BCY 13	Sie	Si-N	LF, 60/60/10V, 0,2A, 0,45W, 0,4MHz		2a	≈TO-39			BC 140…141, BC 637, BC 639, 2SD1211,++
BCY 14	Sie	Si-N	=BCY 14: 100/100/10V		2a	≈TO-39			BC 141, BC 639, 2SD667, 2SD1211,++
BCY 15	Sie	Si-N	=BCY 13: 0,3A		2a	≈TO-39			BC 140…141, BC 637, BC 639, 2SD1212,++
BCY 16	Sie	Si-N	=BCY 13: 100/100/10V, 0,3A		2a	≈TO-39			BC 141, BC 639, 2SD667, 2SD1211,++
BCY 17	Sie,Tag	Si-P	LF,S, 30/30/30V, 0,05/0,2A, 0,35W, 1,2MHz		2a	TO-5			BC 213, BC 257, BC 307, BC 557, 2SB725++
BCY 18	Sie,Tag	Si-P	LF,S, 30/30/30V, 0,05/0,2A, 0,35W, 2MHz		2a	TO-5			BC 213, BC 257, BC 307, BC 557, 2SB725++
BCY 19	Sie,Tag	Si-P	LF,S, 50/50/30V, 0,05/0,2A, 0,35W, 0,8MHz		2a	TO-5			BC 212, BC 257, BC 307, BC 557, 2SB725++
BCY 20	Sie,Tag	Si-P	LF,S, 100/100/50V, 0,05/0,2A, 0,35W, 0,5MHz		2a	TO-5			2N5400…5401, 2SA1335, 2SB715…716, ++
BCY 21	Tag	Si-P	LF,S, 50/50/30V, 0,05/0,2A, 0,35W, 0,5MHz		2a	TO-5			BC 212, BC 257, BC 307, BC 557, 2SB725++
BCY 22	Tag	Si-P	LF,S, 75/75/50V, 0,05/0,2A, 0,35W, 0,5MHz		2a	TO-5			BC 256, BC 266, BC 556, 2SB715…716,++
BCY 23	Tag	Si-P	LF,S, 30/10/30V, 0,05/0,2A, 0,35W, 1,5MHz		2a	TO-5			BC 213, BC 258, BC 308, BC 558, 2SB725++
BCY 24	Tag	Si-P	LF,S, 30/10/30V, 0,05/0,2A, 0,35W, 1MHz		2a	TO-5			BC 213, BC 258, BC 308, BC 558, 2SB725++
BCY 25	Tag	Si-P	LF,S, 30/10/30V, 0,05/0,2A, 0,35W, 2,5MHz		2a	TO-5			BC 213, BC 258, BC 308, BC 558, 2SB725++
BCY 26	Tag	Si-P	LF,S, 30/30/30V, 0,05/0,2A, 0,35W, 0,6MHz		2a	TO-5			BC 213, BC 258, BC 308, BC 558, 2SB725++
BCY 27	Sie,Tag	Si-P	LF,S, 30/25/30V, 0,05/0,2A, 0,275W, 1MHz		2a	TO-5			BC 213, BC 258, BC 308, BC 558, 2SB725++
BCY 28	Sie,Tag	Si-P	LF,S, 30/25/30V, 0,05/0,2A, 0,275W, 1,5MHz		2a	TO-5			BC 213, BC 258, BC 308, BC 558, 2SB725++
BCY 29	Sie,Tag	Si-P	LF,S, 60/60/30V, 0,05/0,2A, 0,275W, 0,5MHz		2a	TO-5			BC 212, BC 256, BC 266, BC 556, 2SB725++
BCY 30	Phi,Tag	Si-P	LF,S, 64/50/45V, 0,05/0,1A, 0,25W, 1,2MHz		2a	TO-5			BC 212, BC 256, BC 266, BC 556, 2SB725++
BCY 30 A		Si-P	=BCY 30: 0,1A, 0,6W, 7MHz		2a	TO-5			BC 212, BC 256, BC 266, BC 556, 2SB725++
BCY 31	Phi,Tag	Si-P	LF,S, 64/50/45V, 0,05/0,1A, 0,25W, 1,7MHz		2a	TO-5			BC 212, BC 256, BC 266, BC 556, 2SB725++
BCY 31 A		Si-P	=BCY 31: 0,1A, 0,6W, 7MHz		2a	TO-5			BC 212, BC 256, BC 266, BC 556, 2SB725++
BCY 32	Phi,Tag	Si-P	LF,S, 64/50/32V, 0,05/0,1A, 0,25W, 2,5MHz		2a	TO-5			BC 212, BC 256, BC 266, BC 556, 2SB725++
BCY 32 A		Si-P	=BCY 32: 0,1A, 0,6W, 7MHz		2a	TO-5			BC 212, BC 256, BC 266, BC 556, 2SB725++
BCY 33	Phi,Tag	Si-P	LF,S, 32/25/16V, 0,05/0,1A, 0,25W, 1,5MHz		2a	TO-5			BC 213, BC 258, BC 308, BC 558, 2SB725++
BCY 33 A		Si-P	=BCY 33: 0,1A, 0,6W, 7MHz		2a	TO-5			BC 213, BC 258, BC 308, BC 558, 2SB725++
BCY 34	Phi,Tag	Si-P	LF,S, 32/25/16V, 0,05/0,1A, 0,25W, 2,4MHz		2a	TO-5			BC 213, BC 258, BC 308, BC 558, 2SB725++
BCY 34 A		Si-P	=BCY 34: 0,1A, 0,6W, 7MHz		2a	TO-5			BC 213, BC 258, BC 308, BC 558, 2SB725++
BCY 38	Phi,Tix	Si-P	LF, 32/24/12V, 0,25/0,5A, 0,35W, 1,5MHz		2a(B=Case)	TO-5			BC 328, BC 636, BC 638, 2SA1515,++
BCY 39	Phi,Tix	Si-P	LF, 64/60/12V, 0,25/0,5A, 0,35W, 1,5MHz		2a(B=Case)	TO-5			BC 638, BC 640, 2N2904…2905, 2SA1533,++
BCY 40	Phi,Tix	Si-P	LF, 64/60/12V, 0,25/0,5A, 0,35W, 2,5MHz		2a(B=Case)	TO-5			BC 638, BC 640, 2N2904…2905, 2SA1533,++
BCY 42(P)	Fer,Itt,Sgs	Si-N	Uni, 40/25V, 0,2A, 0,3W, >100MHz, hFE=45…90		2a	TO-18			BC 167, BC 183, BC 237, BC 547, 2SD767++
BCY 43(P)	Fer,Itt,Sgs	Si-N	=BCY 42: hFE=75…150		2a	TO-18			BC 167, BC 183, BC 237, BC 547, 2SD767++
BCY 49	Phi	Si-P	LF, sym, 15/15/15V, 20mA, 0,25W		2a	TO-5			-
BCY 50(r,i)	Itt	Si-N	LF Inp, 10/5V, 0,1A, 0,3W, >60MHz, r: <5dB(1kHz)		2a	TO-18	BC 550	7a	BC 169, BC 184, BC 239, BC 549, 2SC2675+

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BCY 51(r.i)	Itt	Si-N	=BCY 50: 30/20V, >50MHz, i=Iso		2a	TO-18	BC 550	7a	BC 169, BC 184, BC 239, BC 549, 2SC2675+
BCY 54	Phi	Si-P	LF, 50/50/12V, 0,25/0,5A, 0,35W, 2MHz		2a(B=Case)	TO-5			BC 327, BC 638, BC 640, 2N2904…2905, ++
BCY 55	Phi	Si-N	Dual, In, 45/45V, 30/60mA, 0,3W, 80MHz		2x 2a°	2xTO-18			-
BCY 56	Phi,Sgs,Tix	Si-N	LF In, 45/45V, 0,1/0,2A, 0,3W, 250MHz, F<5dB(1kHz)		2a	TO-18			BC 184, BC 413…414, BC 550, 2SC2675,++
BCY 57	Phi,Sgs,Tix	Si-N	=BCY 56/20: 25/20V, 350MHz		2a	TO-18			BC 169, BC 184, BC 239, BC 549, 2SC2675+
BCY 58	EUR	Si-N	LF,S, 32/32V, 0,2A, 0,39W, 250MHz	{BCY78	2a	TO-18	BC 546	7a	BC 183, BC 548, BCX 58, 2N2221…2222, ++
BCY 58 P	Fer	Si-N	=BCY 58:		40e	≈TO-92	›BCY 58		›BCY 58
BCY 59	EUR	Si-N	=BCY 58: 45/45V	{BCY79	2a	TO-18	BC 546	7a	BC 182, BC 547, BCX 59, 2N2221…2222, ++
BCY 59 P	Fer	Si-N	=BCY 59:		40e	≈TO-92	›BCY 59		›BCY 59
BCY 65	EUR	Si-N	LF,S, 60/60V, 0,1A, 250MHz, 65/450ns	{BCY77	2a	TO-18	BC 546	7a	BC 182, BC 546, 2N2221…2222, 2SD767,++
BCY 65 P	Fer	Si-N	=BCY 65:		40e	≈TO-92	›BCY 65		›BCY 65
BCY 66	Sie	Si-N	LF In, 45/45V, 0,05A, 1(Tc=45°), 250MHz	{BCY67	2a	TO-18			BC 184, BC 413…414, BC 550, 2SC2675,++
BCY 67	Sie	Si-P	LF In, 45/45V, 0,05A, 1(Tc=45°), 180MHz	{BCY66	2a	TO-18			BC 214, BC 415…416, BC 560, 2SA1137,++
BCY 69	Tix,Tho	Si-N	LF, 20/20V, 0,1A, 0,3W, >150MHz		2a	TO-18			BC 168, BC 183, BC 238, BC 548, 2SD767++
BCY 70(P)	EUR	Si-P	LF,S, 50/40V, 0,2A, 0,35W, 450MHz, 48/320ns		2a	TO-18			BCX 79, BCY 79, 2N2906…2907, 2SB725,++
BCY 71(A,AP)	EUR	Si-P	=BCY 70, In, 45/45V, F<2dB(1kHz)		2a	TO-18			BC 214, BC 415…416, BC 560, 2SA1137,++
BCY 72(P)	EUR	Si-P	=BCY 70: 30/25V		2a	TO-18			BCX 78, BCY 78, 2N2906…2907, 2SB725,++
BCY 76	Mic	Si-N	Uni, 45/45V, 0,1A, 0,3W, 40MHz		2a	TO-18			BC 167, BC 182, BC 237, BC 547, 2SD767++
BCY 77	EUR	Si-P	LF,S, 60/60V, 0,1A, 0,35W, 180MHz, 65/450ns	{BCY65	2a	TO-18	BC 556	7a	BC 212, BC 556, 2N2906A…07A, 2SB725,++
BCY 77 P	Fer	Si-P	=BCY 77:		40e	≈TO-92	›BCY 77		›BCY 77
BCY 78	EUR	Si-P	=BCY 77: 32/32V, 55/450ns	{BCY58	2a	TO-18	BC 556	7a	BC 213, BC 558, BCX 78, 2N2906…2907, ++
BCY 78 P	Fer	Si-P	=BCY 78:		40e	≈TO-92	›BCY 78		›BCY 78
BCY 79	EUR	Si-P	=BCY 77: 45/45V	{BCY59	2a	TO-18	BC 556	7a	BC 213, BC 557, BCX 79, 2N2906…2907, ++
BCY 79 P	Fer	Si-P	=BCY 79:		40e	≈TO-92	›BCY 79		›BCY 79
BCY 85	Tix	Si-N	LF,S, 100/60V, 0,2A, 0,3W, >200MHz, 28/69ns		7a	SOT-30	2SC2632	7c(9mm)	2SC2240, 2SC2459, 2SC2675, 2SC3378,++
BCY 86	Tix	Si-N	=BCY 85: 80/50V		7a	SOT-30	BC 546	7a	BC 546, 2SC2240, 2SC2459, 2SC3378,++
BCY 87	Nsc,Phi,Tix	Si-N	Dual, In, 45/40V, 30mA, 0,15W, >50MHz, ΔUbe<3mV		TO-71	(EECBBC)			-
BCY 88	Nsc,Phi,Tix	Si-N	=BCY 87: ΔUbe<6mV		TO-71	(EECBBC)			-
BCY 89	Nsc,Phi,Tix	Si-N	=BCY 87: ΔUbe<10mV		TO-71	(EECBBC)			-
BCY 90(B)	Tag	Si-P	LF,S, 40/40/20V, 0,05/0,1A, 0,35W, 15MHz, B=TO-39		2a	TO-18/-39			BC 212, BC 257, BC 307, BC 557, 2SB725++
BCY 91(B)	Tag	Si-P	LF,S, 40/40/20V, 0,05/0,1A, 0,35W, 15MHz, B=TO-39		2a	TO-18/-39			BC 212, BC 257, BC 307, BC 557, 2SB725++
BCY 92(B)	Tag	Si-P	LF,S, 40/40/20V, 0,05/0,1A, 0,35W, 15MHz, B=TO-39		2a	TO-18/-39			BC 212, BC 257, BC 307, BC 557, 2SB725++
BCY 93(B)	Tag	Si-P	LF,S, 70/70/30V, 0,05/0,1A, 0,35W, 15MHz, B=TO-39		2a	TO-18/-39			BC 212, BC 256, BC 266, BC 556, 2SA1137+
BCY 94(B)	Tag	Si-P	LF,S, 70/70/30V, 0,05/0,1A, 0,35W, 15MHz, B=TO-39		2a	TO-18/-39			BC 212, BC 256, BC 266, BC 556, 2SA1137+
BCY 95(B)	Tag	Si-P	LF,S, 70/70/30V, 0,05/0,12A, 0,35W, 15MHz, B=TO-39		2a	TO-18/-39			BC 212, BC 256, BC 266, BC 556, 2SA1137+
BCY 96(B)	Tag	Si-P	LF,S, 90/90/30V, 0,05/0,1A, 0,35W, 15MHz, B=TO-39		2a	TO-18/-39			BC 556, 2SA893, 2SA1016, 2SA1038, ++
BCY 97(B)	Tag	Si-P	LF,S, 90/90/30V, 0,05/0,1A, 0,35W, 15MHz, B=TO-39		2a	TO-18/-39			BC 556, 2SA893, 2SA1016, 2SA1038, ++
BCY 98(B)	Tag	Si-P	LF,S, 40/40/20V, 0,05/0,1A, 0,35W, 15MHz, B=TO-39		2a	TO-18/-39			BC 213, BC 257, BC 307, BC 557, 2SB725++
BCY 99(B)	Tag	Si-P	LF,S, 70/70/30V, 0,05/0,1A, 0,35W, 15MHz, B=TO-39		2a	TO-18/-39			BC 212, BC 256, BC 266, BC 556, 2SB725++
BCZ									
BCZ 10	Phi,Mot	Si-P	LF, 25/25/20V, 0,05A, 0,21W, hfe=15…60		1a	(15x6mmØ)	BC 556	7a	BC 213, BC 258, BC 308, BC 558, 2SB725++
BCZ 11	Phi,Mot	Si-P	=BCZ 10: hfe=25…60		1a	(15x6mmØ)	BC 556	7a	BC 213, BC 258, BC 308, BC 558, 2SB725++
BCZ 12	Phi,Mot	Si-P	=BCZ 10: 60V, hfe=15>10		1a	(15x6mmØ)	BC 556	7a	BC 212, BC 256, BC 266, BC 556, 2SB725++
BCZ 13	Phi	Si-P	Min, LF, 20/20/20V, 10mA, 85mW, hfe=15…60		37a	SOT-19	(BC 556)[6]	7a	(BC213, BC258, BC308, BC558, 2SB725,++)[6]
BCZ 14	Phi	Si-P	=BCZ 13: hfe=30…90		37a	SOT-19	(BC 556)[6]	7a	(BC213, BC258, BC308, BC558, 2SB725,++)[6]
BD									
BD		Si-Di	=1SS271 (SMD-Marking)		35	SOT-23			›1SS271
BD		Si-P	=2SB1121 (SMD-Marking)		39	SOT-89			›2SB1121
BD		Si-P	=2SB1189 (SMD-Marking)		39	SOT-89			›2SB1189
BD		Si-N	=BCP 54-16 (SMD-Marking)		≈39°	SOT-223			›BCP 54-16
BD(p.s)		Si-P	=BCW 61D(SMD-Marking)		35	SOT-23			›BCW 61D
BD		Si-N	=BCX 54-16 (SMD-Marking)		39	SOT-89			›BCX 54-16
BD/1	Hfo	Se-Di	Blitzschutz/Lightning Protect Di, Ubr=75V(400mA)		12	(17x20x6)			-
BD 04	Fui	Hybrid-IC	Plasma-Anzeige-Treiber/Plasma Display Drv						-
BD 106	Itt	Si-N	LF P, 36/36V, 2,5A, 11,5W, 100MHz		22a	SOT-9	2SC1398	17j	BDW 25, 2SC3252, 2SD1505, 2SD1912,++
BD 107	Itt	Si-N	=BD 106: 64/64V		22a	SOT-9	2SC1398	17j	BDW 25, 2SC3252, 2SD1505, 2SD1912,++
BD 109	Sie	Si-N	P, 60/40V, 3A, 18,5W, >30MHz, <300/1500ns		22a	SOT-9	BD 243 C	17j	BDW 25, 2SC3252…53, 2SD1505, 2SD1912,++
BD 111	Sgs	Si-N	S P, TV-VA, 60/60V, 10A, 15W(Tc=75°), 60MHz		23a	TO-3	2SC2837	18j	BDY 90…92, 2SC2681, 2SC3256,++ (BD245+)[8]
BD 111 A		Si-N	=BD 111: 62,5W		23a	TO-3	2SC2837	18j	BDY 90…92, 2SC2681, 2SC3256,++ (BD245+)[8]
BD 112	Sgs	Si-N	LF P, 80/60V, 2A, 15W(Tc=75°), >30MHz		23a	TO-3	2SC2837	18j	BDY 90…92, 2SC2681, 2SC3256,++(BD245B+)[8]
BD 113	Sgs	Si-N	LF P, 60/60V, 10A, 15W(Tc=75°), >60MHz		23a	TO-3	2SC2837	18j	BDY 90…92, 2SC2681, 2SC3256,++ (BD245+)[8]
BD 115	Phi,Tho	Si-N	LF, Vid, 245/180V, 0,15/0,2A, 0,8W, 145MHz		2a	TO-39	MPS-U10[6]	13m	BF 381, BF 615, BFR 58…59, MPS-U10, ++
BD 116	Sgs	Si-N	LF P, 80/60V, 3A, 15W(Tc=75°), >30MHz		23a	TO-3	2SC2837	18j	BDY 90…92, 2SC2681, 2SC3256,++(BD245B+)[8]
BD 117	Sgs	Si-N	LF P, 100/60V, 5/10A, 30W(Tc=50°), 50MHz		23a	TO-3	2SC2837	18j	BDY 90…91, 2SC2681, 2SC2837,++(BD245C+)[8]
BD 118	Sgs	Si-N	LF P, 80V, 15W(Tc=75°), >30MHz		23a	TO-3	2SC2837	18j	BDY 90…92, 2SC2681, 2SC3256,++(BD245B+)[8]
BD 119	Sgs	Si-N	LF,Vid P, 300/300V, 0,4A, 6W(Tc=75°), 70MHz		22a	TO-66	(BUX 85)	17j	2SC782, 2SC1929, 2SC2022, 2SC2354, ++
BD 120	Sgs	Si-N	LF,Vid P, 150/150V, 0,15A, 7,5W(Tc=75°), >30MHz		22a	TO-66	2SC1505	17j	2SC1505…1507, 2SC1755…1757, 2SC1905,++
BD 121	Phi	Si-N	LF P, 60/35V, 5A, 45W, 85MHz		23a	TO-3	2SC2837	18j	BDY 90…92, 2SC2681, 2SC3256,++(BD245A+)[8]
BD 123	Phi	Si-N	=BD 121: 90/60V		23a	TO-3	2SC2837	18j	BDY 90…91, 2SC2681, 2SC2837,++(BD245C+)[8]
BD 124(A)	Phi	Si-N	LF P, 70/45V, 2/4A, 10W(Tc=100°), 120MHz		22a	SOT-9	2SC1398	17j	BDW 25, BDX 25, 2SC1398, 2SC3252, ++
BD 127	Aeg	Si-N	LF,Vid P, 300/250V, 0,5A, 17,5W(Tc=45°)		14h	TO-126	MJE 340	14h	BF 758, MJE 340, 2SC3051, 2SD1971, ++
BD 128	Aeg	Si-N	=BD 127: 350/300V		14h	TO-126	(MJE 340)	14h	BF 759, MJE 340, 2SC3051, 2SD1971, ++
BD 129	Aeg	Si-N	=BD 127: 400/350V		14h	TO-126	(MJE 340)[7]	14h	2SC2899, 2SC3051, 2SC3425, 2SD1971
BD 127…129	Aeg	Si-N	=: -/0,25A, 16,5W		22a	SOT-9			
BD 130	Rca,Sgs,Sie	Si-N	=2N3055		23a	TO-3	›2N3055		›2N3055
BD 130 Y		Si-N	=BD 130: 60/45V		23a	TO-3	›2N3055		›2N3055
BD 131(A)	Phi	Si-N	LF P, 70/45(A=70/60)V, 3/6A, 15W(Tc=60°), >60MHz		14h	TO-126	BD 237	14h	BD 237, BD 441, BD 787, BD 789, ++
BD 132(A)	Phi	Si-P	LF P, 45/45(A=70/60)V, 3/6A, 15W(Tc=60°), >60MHz		14h	TO-126	BD 238	14h	BD 238, BD 440, BD 786, BD 788, ++
BD 133	Phi	Si-N	=BD 131: 90/60V		14h	TO-126	BD 237	14h	BD 237, BD 443, BD 791, BDX 35…37, ++
BD 134		Si-P	=BD 238		14h	TO-126	›BD 238		›BD 238
BD 135(H)	EUR	Si-N	P, 45/45V, 1,5/2A, 12,5W(Tc=45°), >50MHz	{BD136	14h	TO-126	BD 139	14h	BD 226, BD 375, BD 785, 2SC2690(A),++
BD 135G	Gen	Si-N	=BD 135:		13j	TO-202	(BD 139)[5]	14h	2SC1848, 2SC2483
BD 136(H)	EUR	Si-P	P, 45/45V, 1,5/2A, 12,5W(Tc=45°), >50MHz	{BD135	14h	TO-126	BD 140	14h	BD 227, BD 376, BD 786, 2SA1220(A),++
BD 136 G	Gen	Si-P	=BD 136:		13j	TO-202	(BD 140)[5]	14h	2SA887, 2SA1195
BD 137(H)	EUR	Si-N	=BD 135: 60/60V	{BD138	14h	TO-126	BD 139	14h	BD 228, BD 377, BD 785, 2SC2690(A),++
BD 137 G	Gen	Si-N	=BD 137:		13j	TO-202	(BD 139)[5]	14h	2SC1848, 2SC2483
BD 138(H)	EUR	Si-P	=BD 136: 60/60V	{BD137	14h	TO-126	BD 140	14h	BD 229, BD 378, BD 786, 2SA1220(A),++
BD 138 G	Gen	Si-P	=BD 138:		13j	TO-202	(BD 140)[5]	14h	2SA887, 2SA1195
BD 139(H)	EUR	Si-N	=BD 135: 100/80V	{BD140	14h	TO-126	BD 139	14h	BD 230, BD 379, BD 791, 2SC2690(A),++
BD 139 G	Gen	Si-N	=BD 139:		13j	TO-202	(BD 139)[5]	14h	2SC2483
BD 140(H)	EUR	Si-P	=BD 136: 100/80V	{BD139	14h	TO-126	BD 140	14h	BD 231, BD 380, BD 792, 2SA1220(A),++

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BD 140 G	Gen	Si-P	=BD 140:		13j	TO-202	(BD 140)[5]	14h	2SA1195
BD 141	Sgs	Si-N	LF P, 140/120V, 8/13A, 117W, >0,8MHz		23a	TO-3	2SD1047	18j	BDX 11…12, BDX 51, 2N5634, 2SD551, ++
BD 142	Mot,Rca,Tho	Si-N	LF,S P, 50/40V, 15A, 117W, 1,3MHz		23a	TO-3	2N3055	23a	BDW 51, BDX 13, BDX 60…61, 2N3055, ++
BD 144	Phi	Si-N	TV-VA, 800/400V, 0,25A, 8W(Tc=95°), 12MHz		23a	TO-3			2SC1101, 2SC3151, 2SC3533
BD 145	Phi	Si-N	TV-HA, 150/60V, 5/10A, 15W(Tc=100°), 100MHz		23a	TO-3	BU 608	23a	BU 104, BU 606…608
BD 148	Sie	Si-N	LF,S P, 60/40V, 4A, 31W(Tc=45°), 1MHz		22a	SOT-9	BD 243 C	17j	BD 243A…C, BD 543A…D, 2N3054, ++
BD 149	Sie	Si-N	=BD 148: 80/60V		22a	SOT-9	BD 243 C	17j	BD 243B…C, BD 543B…D, 2N3054, ++
BD 150(A….C)	Sgs	Si-N	Vid, 200…300V, 0,5A, 1W, 160MHz A=150/200V, B=190/250V, C=220/300V		2a	TO-39	MPS-U10[6]	13m	BF 382, BF 758…759, MPS-U10, ++
BD 151	Mot	Si-P	LF P, 35/30V, 1A, 20W	{BD153	14h	TO-126	BD 140	14h	BD 136, BD 227, BD 376, BD 786, 2SA1220+
BD 152	Mot	Si-P	=BD 151: 50/45V	{BD154	14h	TO-126	BD 140	14h	BD 138, BD 229, BD 378, BD 788, 2SA1220+
BD 153	Mot	Si-N	LF P, 35/30V, 1A, 20W	{BD151	14h	TO-126	BD 139	14h	BD 135, BD 226, BD 375, BD 785, 2SC2690+
BD 154	Mot	Si-N	=BD 153: 50/45V	{BD152	14h	TO-126	BD 139	14h	BD 137, BD 228, BD 375, BD 785, 2SC2690+
BD 155	Mot	Si-N	=BD 153: 70/60V	{BD156	14h	TO-126	BD 139	14h	BD 139, BD 230, BD 377, BD 787, 2SC2690+
BD 156	Mot	Si-P	=BD 151: 70/60V	{BD155	14h	TO-126	BD 140	14h	BD 140, BD 231, BD 378, BD 790, 2SA1220+
BD 157	Mot,Nsc,Tho	Si-N	LF,Vid P, 275/250V, 0,5/1A, 20W		14h	TO-126	MJE 340	14h	BF 758…759, MJE 340, 2SC2899, 2SC3051
BD 158	Mot,Nsc,Tho	Si-N	=BD 157: 325/300V		14h	TO-126	MJE 340	14h	BF 759, MJE 340, 2SC2899, 2SC3051
BD 159	Mot,Nsc,Tho	Si-N	=BD 157: 375/350V		14h	TO-126	MJE 340	14h	BF 759, MJE 340, 2SC2899, 2SC3051
BD 160	Phi	Si-N	TV-HA, 250/200V, 5/7A, 25W		23a	TO-3	BU 608	23a	BU 104, BU 606…608
BD 161	Sgs	Si-N	LF,S P, 90/55V, 4A, 19W(Tc=85°), 1,75MHz		22a	SOT-9	BD 243 C	17j	BD 243C, BD 543C…D, BD 953, 2N3054, ++
BD 162	Sgs	Si-N	=BD 161: 40/20V		22a	SOT-9	BD 243 C	17j	BD 243, BD 543, BD 947, 2N3054, ++
BD 163	Sgs	Si-N	=BD 161: 60/40V		22a	SOT-9	BD 243 C	17j	BD 243A…C, BD 543A…D, BD 949, 2N3054
BD 165	EUR	Si-N	LF P, 45/45V, 1,5/3A, 20W, >3MHz	{BD166	14h	TO-126	BD 237	14h	BD 175, BD 226, BD 233, BD 437, 2SC2690+
BD 166	EUR	Si-P	LF P, 45/45V, 1,5/3A, 20W, >3MHz	{BD165	14h	TO-126	BD 238	14h	BD 176, BD 227, BD 234, BD 438, 2SA1220+
BD 167	EUR	Si-N	=BD 165: 60/60V	{BD168	14h	TO-126	BD 237	14h	BD 177, BD 228, BD 235, BD 439, 2SC2690+
BD 168	EUR	Si-P	=BD 166: 60/60V	{BD167	14h	TO-126	BD 238	14h	BD 178, BD 229, BD 236, BD 440, 2SA1220+
BD 169	EUR	Si-N	=BD 165: 80/80V	{BD170	14h	TO-126	BD 237	14h	BD 179, BD 230, BD 237, BD 441, 2SC2690+
BD 170	EUR	Si-P	=BD 166: 80/80V	{BD169	14h	TO-126	BD 238	14h	BD 180, BD 231, BD 238, BD 442, 2SA1220+
BD 171	Aeg,Mot	Si-N	LF P, 100/90V, 0,5/1A, 20W, 6MHz		14h	TO-126	2SC3116	14h	BD 139, BD 237, 2SC2690(A), 2SD1382,++
BD 172	Aeg,Mot	Si-N	=BD 171: 130/120V		14h	TO-126	2SC3116	14h	BD 524, 2SC2690(A), 2SC2803, 2SC3116, ++
BD 173	Aeg,Mot	Si-N	=BD 171: 170/160V		14h	TO-126	2SC3116	14h	MJE 340, 2SC3116…17, 2SD669, ++
BD 175	Aeg,Mot,++	Si-N	LF P, 45/45V, 3/7A, 30W, >3MHz	{BD176	14h	TO-127	BD 189	14h	BD 185, BD 437, BD 785, 2N5190…5192, ++
BD 176	Aeg,Mot,++	Si-P	LF P, 45/45V, 3/7A, 30W, >3MHz	{BD175	14h	TO-126	BD 190	14h	BD 186, BD 438, BD 786, 2N5193…5195, ++
BD 177	Aeg,Mot,++	Si-N	=BD 175: 60/60V	{BD178	14h	TO-126	BD 189	14h	BD 187, BD 439, BD 787, 2N5191…5192, ++
BD 178	Aeg,Mot,++	Si-P	=BD 176: 60/60V	{BD177	14h	TO-126	BD 190	14h	BD 188, BD 440, BD 788, 2N5194…5195, ++
BD 179	Aeg,Mot,++	Si-N	=BD 175: 80/80V	{BD180	14h	TO-126	BD 189	14h	BD 189, BD 441, BD 791, 2N5192, ++
BD 180	Aeg,Mot,++	Si-P	=BD 176: 80/80V		14h	TO-126	BD 190	14h	BD 190, BD 442, BD 792, 2N5195, ++
BD 181	Phi,Rca,Tho	Si-N	LF P, 55/45V, 10/15A, 117W		23a	TO-3	2N3055	23a	BD 245, BD 311, BDY 39, 2N3055, ++
BD 182	Phi,Rca,Tho	Si-N	=BD 181: 70/60V, 15A		23a	TO-3	2N3055	23a	BD 745A, BD 315, BDY 39, 2N3055, ++
BD 183	Phi,Rca,Tho	Si-N	=BD 181: 85/80V, 15A		23a	TO-3	2N3055	23a	BD 745B, BD 317, BDY 39, 2N3055, ++
BD 184	Phi,Rca,Tho	Si-N	=BD 181: 95/90V, 15A		23a	TO-3	2N3055	23a	BD 745C, BD 317, BDY 39, 2N3055, ++
BD 185	Aeg,Mot	Si-N	LF P, 40/30V, 4/8A, 40W, >2MHz	{BD186	14h	TO-126	BD 189	14h	BD 437, BD 785, 2N5190
BD 186	Aeg,Mot	Si-P	LF P, 40/30V, 4/8A, 40W, >2MHz	{BD185	14h	TO-126	BD 190	14h	BD 438, BD 786, 2N5193
BD 187	Aeg,Mot	Si-N	=BD 185: 55/45V	{BD188	14h	TO-126	BD 189	14h	BD 439, BD 785, 2N5191
BD 188	Aeg,Mot	Si-P	=BD 186: 55/45V	{BD187	14h	TO-126	BD 190	14h	BD 440, BD 786, 2N5194
BD 189	Aeg,Mot	Si-N	=BD 185: 70/60V	{BD190	14h	TO-126	BD 189	14h	BD 441, BD 787, 2N5192
BD 190	Aeg,Mot	Si-P	=BD 186: 70/60V	{BD189	14h	TO-126	BD 190	14h	BD 442, BD 788, 2N5195
BD 191	Sgs	Si-N	LF,S P, 100/60V, 15A, 37,5W, >0,8MHz		22a	SOT-9	(BD 245 C)[4]	18j	BD 743C, BD 911, BDT 85
BD 192	Sgs	Si-N	=BD 191: 50/40V		22a	SOT-9	(BD 245 C)[4]	18j	BD 743A, BD 907, BDT 81
BD 193	Sgs	Si-N	=BD 191: 140/120V, 8/13A		22a	SOT-9	2SC2334	17j	MJE 15030, 2SC2334, 2SC4329…30
BD 195	Mot	Si-N	LF P, 40/30V, 6A, 65W, >2MHz	{BD196	16h	TO-127	(BD 243 C)[5]	17j	BD 205, MJE 3055, 2N5983, 2SD499
BD 196	Mot	Si-P	LF P, 40/30V, 6A, 65W, >2MHz	{BD195	16h	TO-127	(BD 244 C)[5]	17j	BD 206, MJE 2955, 2N5980, 2SB578
BD 197	Mot	Si-N	=BD 195: 55/45V	{BD198	16h	TO-127	(BD 243 C)[5]	17j	BD 205, MJE 3055, 2N5983, 2SD499
BD 198	Mot	Si-P	=BD 196: 55/45V	{BD197	16h	TO-127	(BD 244 C)[5]	17j	BD 206, MJE 2955, 2N5980, 2SB578
BD 199	Mot	Si-N	=BD 195: 70/60V	{BD200	16h	TO-127	(BD 243 C)[5]	17j	BD 207, MJE 3055, 2N5984, 2SD500
BD 200	Mot	Si-P	=BD 196: 70/60V	{BD199	16h	TO-127	(BD 244 C)[5]	17j	BD 208, MJE 2955, 2N5981, 2SB578
BD 201	Aeg,Phi,Rca	Si-N	LF P, 60/45V, 8/12A, 60W, >7MHz, <1/4µs	{BD202	17j	TO-220	BD 243 C	17j	BD 243A, BD 543A, BD 707, BD 797, ++
BD 201 F	Phi	Si-N	=BD 201: Iso, >20W		17c	SOT-186	2SD1411	17c	BDT 91F, BDX 77F, 2SD1411…12, 2SD1668++
BD 202	Aeg,Phi,Rca	Si-P	LF P, 60/45V, 8/12A, 60W, >7MHz, <1/2µs	{BD201	17j	TO-220	BD 244 C	17j	BD 244A, BD 544A, BD 708, BD 798, ++
BD 202 F	Phi	Si-P	=BD 202: Iso, >20W		17c	SOT-186	2SB1018	17c	BDT 92F, BDX 78F, 2SB1018…19, 2SB1135++
BD 203	Aeg,Phi,Rca	Si-N	=BD 201: 60/60V	{BD204	17j	TO-220	BD 243 C	17j	BD 243A, BD 543A, BD 707, BD 797, ++
BD 203 F	Phi	Si-N	=BD 203: Iso, >20W		17c	SOT-186	2SD1411	17c	BDT 91F, BDX 77F, 2SD1411…12, 2SD1668++
BD 204	Aeg,Phi,Rca	Si-P	=BD 202: 60/60V	{BD203	17j	TO-220	BD 244 C	17j	BD 244A, BD 544A, BD 708, BD 798, ++
BD 204 F	Phi	Si-P	=BD 204: Iso, >20W		17c	SOT-186	2SB1018	17c	BDT 92F, BDX 78F, 2SB1018…19, 2SB1135++
BD 205	Mot	Si-N	LF P, 55/45V, 10A, 90W, 4MHz	{BD206	16h	TO-127	(BD 809)[5]	17j	MJE 3055, 2N5989, 2SD491
BD 206	Mot	Si-P	LF P, 55/45V, 10A, 90W, 4MHz	{BD205	16h	TO-127	(BD 810)[5]	17j	MJE 2955, 2N5986, 2SB578
BD 207	Mot	Si-N	=BD 205: 70/60V	{BD208	16h	TO-127	(BD 809)[5]	17j	MJE 3055, 2N5990, 2SD491
BD 208	Mot	Si-P	=BD 206: 70/60V	{BD207	16h	TO-127	(BD 810)[5]	17j	MJE 2955, 2N5987, 2SB578
BD 209…212	Aeg	Si							
BD 213/45…80	Aeg	Si-N	LF P, 45/45…80/80V, 15/15A, 90W, >3MHz	{BD214	18j	TO-3P	BD 245 C	18j	BD 245(A…C), BD 249(A…C), BD 745(A…C)
BD 214/45…80	Aeg	Si-P	LF P, 45/45…80/80V, 15/15A, 90W, >3MHz	{BD213	18j	TO-3P	BD 246 C	18j	BD 246(A…C), BD 250(A…C), BD 746(A…C)
BD 215	Sgs	Si-N	LF P, 500/300V, 0,5A, 21,5W, 10MHz		22a	SOT-9	(BUX 85)	17j	MJ4360…61, 2N4298…99, 2SC1078, 2SC1810
BD 216	Sgs	Si-N	LF P, TV-VA, 300/200V, 1A, 21,5W, 10MHz		22a	SOT-9	(BUX 85)	17j	TIP47…48,2N4296…97,2SC867,2SC2022…23
BD 220	Fch,Mic	Si-N	LF P, 80/70V, 4A, 36W, >0,8MHz	{BD223	17j	TO-220	BD 243 C	17j	BD 243B, BD 537, BD 539B, BD 951, ++
BD 221	Fch,Mic	Si-N	=BD 220: 60/40V	{BD224	17j	TO-220	BD 243 C	17j	BD 243A, BD 535, BD 539A, BD 949, ++
BD 222	Fch,Mic	Si-N	=BD 220: 80/60V	{BD225	17j	TO-220	BD 243 C	17j	BD 243B, BD 537, BD 539B, BD 951, ++
BD 223	Fch,Mic	Si-P	LF P, 80/70V, 4A, 36W, >0,8MHz	{BD220	17j	TO-220	BD 244 C	17j	BD 244B, BD 538, BD 540B, BD 952, ++
BD 224	Fch,Mic	Si-P	=BD 223: 60/40V	{BD221	17j	TO-220	BD 244 C	17j	BD 244A, BD 536, BD 540A, BD 950, ++
BD 225	Fch,Mic	Si-P	=BD 223: 80/60V	{BD222	17j	TO-220	BD 244 C	17j	BD 244B, BD 538, BD 540B, BD 952, ++
BD 226	Phi	Si-N	LF P, 45/45V, 1,5/3A, 12,5W(Tc=62°), 125MHz	{BD227	14h	TO-126	BD 139	14h	BD 135, BD 375, BD 785, 2SC2690(A),++
BD 227	Phi	Si-P	LF P, 45/45V, 1,5/3A, 12,5W(Tc=62°), 50MHz	{BD226	14h	TO-126	BD 140	14h	BD 136, BD 376, BD 786, 2SA1220(A),++
BD 228	Phi	Si-N	=BD 226: 60/60V	{BD229	14h	TO-126	BD 139	14h	BD 137, BD 377, BD 785, 2SC2690(A),++
BD 229	Phi	Si-P	=BD 227: 60/60V	{BD228	14h	TO-126	BD 140	14h	BD 138, BD 378, BD 786, 2SA1220(A),++
BD 230	Phi	Si-N	=BD 226: 100/80V	{BD231	14h	TO-126	BD 139	14h	BD 139, BD 379, BD 791, 2SC2690(A),++
BD 231	Phi	Si-P	=BD 227: 100/80V	{BD230	14h	TO-126	BD 140	14h	BD 140, BD 380, BD 792, 2SA1220(A),++
BD 232	Phi,Mot	Si-N	TV-HA Drv, 500/300V, 0,25/1AA, 15W, 20MHz		14h	TO-126	MJE 340	14h	2SC 2752, 2SC2899, 2SC3051, 2SC3425
BD 232 G	Gen	Si-N	=BD 232: 15W(Tc=25°)		13j	TO-202	(MJE 340)[5]	14h	(2SC 2752, 2SC2899, 2SC3051, 2SC3425)[5]
BD 233	EUR	Si-N	LF P, 45/45V, 2/6A, 25W, >3MHz, 300/1100ns	{BD234	14h	TO-126	BD 237	14h	BD 175, BD 375, BD 437, 2SD1818,++
BD 233 G	Gen	Si-N	=BD 233: 4A, 30W		17j	TO-220	BD 243 C	17j	BD 243, BD 533, BD 539, BD 947, ++
BD 234	EUR	Si-P	LF P, 45/45V, 2/6A, 25W, >3MHz, 300/1100ns	{BD233	14h	TO-126	BD 238	14h	BD 176, BD 376, BD 438, 2SB1217,++
BD 234 G	Gen	Si-P	=BD 234: 4A, 30W		17j	TO-220	BD 244 C	17j	BD 244, BD 534, BD 540, BD 948, ++
BD 235	EUR	Si-N	=BD 233: 60/60V	{BD236	14h	TO-126	BD 237	14h	BD 177, BD 377, BD 439, 2SD1818,++
BD 235 G	Gen	Si-N	=BD 235: 4A, 30W		17j	TO-220	BD 243 C	17j	BD 243A, BD 535, BD 539A, BD 949, ++

Original	Fabric.	Constr.	Info	Compl.	Fig.		JAEGER	Fig.	International
BD 236	EUR	Si-P	=BD 234: 60/60V	BD235	14h	TO-126	BD 238	14h	BD 178, BD 378, BD 440, 2SB1217,++
BD 236 G	Gen	Si-P	=BD 236: 4A, 30W		17j	TO-220	BD 244 C	17j	BD 244A, BD 536, BD 540A, BD 950, ++
BD 237	EUR	Si-N	=BD 233: 100/80V	BD238	14h	TO-126	BD 237	14h	BD 379, BD 443, 2SD1177...1178
BD 237 G	Gen	Si-N	=BD 237: 4A, 30W		17j	TO-220	BD 243 C	17j	BD 243C, BD 539C, BD 953, 2SD712, ++
BD 238	EUR	Si-P	=BD 234: 100/80V	BD237	14h	TO-126	BD 238	14h	BD 380, 2SB874...875
BD 238 G	Gen	Si-P	=BD 238: 4A, 30W		17j	TO-220	BD 244 C	17j	BD 244C, BD 540C, BD 954, 2SB682, ++
BD 239	EUR	Si-N	LF P, 55/45V, 2/4A, 30W, >3MHz, 300/800ns	BD240	17j	TO-220	BD 243 C	17j	BD 241, BD 243, BD 539A, BD 935, ++
BD 239 A		Si-N	=BD 239: 70/60V		17j	TO-220	BD 243 C	17j	BD 241A, BD 243A, BD 539B, BD 937, ++
BD 239 B		Si-N	=BD 239: 90/80V		17j	TO-220	BD 243 C	17j	BD 241B, BD 243B, BD 539C, BD 937, ++
BD 239 C		Si-N	=BD 239: 115/100V		17j	TO-220	BD 243 C	17j	BD 241C, BD 243C, BD 539D, BD 939, ++
BD 239 D		Si-N	=BD 239: 160/120V		17j	TO-220	2SD1138	17j	BD 241D, BD 243D, 2SD759...760, 2SC2529
BD 239 E		Si-N	=BD 239: 180/140V		17j	TO-220	2SD1138	17j	BD 241E, BD 243E, 2SD760, 2SC2660
BD 239 F		Si-N	=BD 239: 200/160V		17j	TO-220	2SD1138	17j	BD 241F, BD 243F, 2SD760, 2SC2660
BD 240	EUR	Si-P	LF P, 55/45V, 2/4A, 30W, >3MHz, 200/400ns	BD239	17j	TO-220	BD 244 C	17j	BD 242, BD 244, BD 540A, BD 936, ++
BD 240 A		Si-P	=BD 240: 70/60V		17j	TO-220	BD 244 C	17j	BD 242A, BD 244A, BD 540B, BD 938, ++
BD 240 B		Si-P	=BD 240: 90/80V		17j	TO-220	BD 244 C	17j	BD 242B, BD 244B, BD 540C, BD 938, ++
BD 240 C		Si-P	=BD 240: 115/100V		17j	TO-220	BD 244 C	17j	BD 242C, BD 244C, BD 540D, BD 940, ++
BD 240 D		Si-P	=BD 240: 160/120V		17j	TO-220	2SB861	17j	BD 242D, BD 244D, 2SB719...720, 2SA1079
BD 240 E		Si-P	=BD 240: 180/140V		17j	TO-220	2SB861	17j	BD 242E, BD 244E, 2SB720, 2SA1133
BD 240 F		Si-P	=BD 240: 200/160V		17j	TO-220	2SB861	17j	BD 242F, BD 244F, 2SB720, 2SA1133
BD 241	EUR	Si-N	LF P, 55/45V, 3/5A, 40W, >3MHz, 300/1000ns	BD242	17j	TO-220	BD 243 C	17j	BD 243, BD 539A, BD 543A, BD 935, ++
BD 241 A		Si-N	=BD 241: 70/60V		17j	TO-220	BD 243 C	17j	BD 243A, BD 539B, BD 543B, BD 937, ++
BD 241 B		Si-N	=BD 241: 90/80V		17j	TO-220	BD 243 C	17j	BD 243B, BD 539C, BD 543C, BD 937, ++
BD 241 C		Si-N	=BD 241: 115/100V		17j	TO-220	BD 243 C	17j	BD 243C, BD 539D, BD 543D, BD 939, ++
BD 241 D		Si-N	=BD 241: 160/120V		17j	TO-220			BD 243D, 2SD772A,B
BD 241 E		Si-N	=BD 241: 180/140V		17j	TO-220			BD 243E, 2SD772A,B
BD 241 F		Si-N	=BD 241: 200/160V		17j	TO-220			BD 243F, 2SD772A,B
BD 242	EUR	Si-P	LF P, 55/45V, 3/5A, 40W, >3MHz, 200/300ns	BD241	17j	TO-220	BD 244 C	17j	BD 244, BD 540A, BD 544A, BD 936, ++
BD 242 A		Si-P	=BD 242: 70/60V		17j	TO-220	BD 244 C	17j	BD 244A, BD 540B, BD 544B, BD 938, ++
BD 242 B		Si-P	=BD 242: 90/80V		17j	TO-220	BD 244 C	17j	BD 244B, BD 540C, BD 544C, BD 938, ++
BD 242 C		Si-P	=BD 242: 115/100V		17j	TO-220	BD 244 C	17j	BD 244C, BD 540D, BD 544D, BD 940, ++
BD 242 D		Si-P	=BD 242: 160/120V		17j	TO-220			BD 244D
BD 242 E		Si-P	=BD 242: 180/140V		17j	TO-220			BD 244E
BD 242 F		Si-P	=BD 242: 200/160V		17j	TO-220			BD 244F
BD 243	EUR	Si-N	LF P, 55/45V, 6/10A, 65W, >3MHz, 300/1000ns	BD244	17j	TO-220	BD 243 C	17j	BD 543A, BD 797, BD 805, 2SD866
BD 243 A		Si-N	=BD 243: 70/60V		17j	TO-220	BD 243 C	17j	BD 543B, BD 799, BD 807, 2SD866
BD 243 B		Si-N	=BD 243: 90/80V		17j	TO-220	BD 243 C	17j	BD 543C, BD 801, BD 809, 2SD866
BD 243 C		Si-N	=BD 243: 115/100V		17j	TO-220	BD 243 C	17j	BD 543D, BD 801, 2SD866
BD 243 D		Si-N	=BD 243: 160/120V		17j	TO-220			BD 743F, 2SC4329
BD 243 E		Si-N	=BD 243: 180/140V		17j	TO-220			-
BD 243 F		Si-N	=BD 243: 200/160V		17j	TO-220			-
BD 244	EUR	Si-P	LF P, 55/45V, 6/10A, 65W, >3MHz, 200/800ns	BD243	17j	TO-220	BD 244 C	17j	BD 544A, BD 798, BD 808, 2SB870
BD 244 A		Si-P	=BD 244: 70/60V		17j	TO-220	BD 244 C	17j	BD 544B, BD 800, BD 810, 2SB870
BD 244 B		Si-P	=BD 244: 90/80V		17j	TO-220	BD 244 C	17j	BD 544C, BD 802, BD 810, 2SB870
BD 244 C		Si-P	=BD 244: 115/100V		17j	TO-220	BD 244 C	17j	BD 544D, BD 802, 2SB870
BD 244 D		Si-P	=BD 244: 160/120V		17j	TO-220			BD 744F
BD 244 E		Si-P	=BD 244: 180/140V		17j	TO-220			-
BD 244 F		Si-P	=BD 244: 200/160V		17j	TO-220			-
BD 245	Tix	Si-N	LF P, 55/45V, 10/15A, 80W, >3MHz, 300/1000ns	BD246	18j	TO-3P	BD 245 C	18j	BD 249, BD 745A, BDV 91, 2SC2681
BD 245 A		Si-N	=BD 245: 70/60V		18j	TO-3P	BD 245 C	18j	BD 249A, BD 745B, BDV 93, 2SC2681
BD 245 B		Si-N	=BD 245: 90/80V		18j	TO-3P	BD 245 C	18j	BD 249B, BD 745C, BDV 95, 2SC2681
BD 245 C		Si-N	=BD 245: 115/100V		18j	TO-3P	BD 245 C	18j	BD 249C, BD 745D, 2SC2681, 2SD1047
BD 245 D		Si-N	=BD 245: 160/120V		18j	TO-3P	2SC3263	18j	BD 249D, BD 745F, 2SC3263, 2SD1047
BD 245 E		Si-N	=BD 245: 180/140V		18j	TO-3P	2SC3263	18j	BD 249E, 2SC3263
BD 245 F		Si-N	=BD 245: 200/160V		18j	TO-3P	2SC3263	18j	BD 249F, 2SC3263
BD 246	Tix	Si-P	LF P, 55/45V, 10/15A, 80W, >3MHz, 200/800ns	BD245	18j	TO-3P	BD 246 C	18j	BD 250, BD 746A, BDV 92, 2SA1141
BD 246 A		Si-P	=BD 246: 70/60V		18j	TO-3P	BD 246 C	18j	BD 250A, BD 746B, BDV 94, 2SA1141
BD 246 B		Si-P	=BD 246: 90/80V		18j	TO-3P	BD 246 C	18j	BD 250B, BD 746C, BDV 96, 2SA1141
BD 246 C		Si-P	=BD 246: 115/100V		18j	TO-3P	BD 246 C	18j	BD 250C, BD 746D, 2SA1141, 2SB817
BD 246 D		Si-P	=BD 246: 160/120V		18j	TO-3P	2SA1294	18j	BD 250D, BD 746F, 2SA1294, 2SB817
BD 246 E		Si-P	=BD 246: 180/140V		18j	TO-3P	2SA1294	18j	BD 250E, 2SA1294
BD 246 F		Si-P	=BD 246: 200/160V		18j	TO-3P	2SA1294	18j	BD 250F, 2SA1294
BD 249	Mot,Tho,Tix	Si-N	LF P, 55/45V, 25/40A, 125W, >3MHz, 300/900ns	BD250	18j	TO-3P	BD 249 C	18j	2SD1049, 2SD1841
BD 249 A		Si-N	=BD 249: 70/60V		18j	TO-3P	BD 249 C	18j	2SD1049, 2SD1841
BD 249 B		Si-N	=BD 249: 90/80V		18j	TO-3P	BD 249 C	18j	2SD1049, 2SD1841
BD 249 C		Si-N	=BD 249: 115/100V		18j	TO-3P	BD 249 C	18j	2SD1049, 2SD1841
BD 249 D		Si-N	=BD 249: 160/120V		18j	TO-3P			-
BD 249 E		Si-N	=BD 249: 180/140V		18j	TO-3P			-
BD 249 F		Si-N	=BD 249: 200/160V		18j	TO-3P			-
BD 250	Mot,Tho,Tix	Si-P	LF P, 55/45V, 25/40A, 125W, >3MHz, 200/400ns	BD249	18j	TO-3P	BD 250 C	18j	2SD1231
BD 250 A		Si-P	=BD 250: 70/60V		18j	TO-3P	BD 250 C	18j	2SB1231
BD 250 B		Si-P	=BD 250: 90/80V		18j	TO-3P	BD 250 C	18j	2SD1231
BD 250 C		Si-P	=BD 250: 115/100V		18j	TO-3P	BD 250 C	18j	2SB1231
BD 250 D		Si-P	=BD 250: 160/120V		18j	TO-3P			-
BD 250 E		Si-P	=BD 250: 180/140V		18j	TO-3P			-
BD 250 F		Si-P	=BD 250: 200/160V		18j	TO-3P			-
BD 251	Sgs	Si-N	LF P, 40/40V, 3A, 20W(Tc=50°), 46MHz		23a	TO-3	2N3055	23a	BD 245, BDY90...92, 2N3055, 2SC3256, ++
BD 253	Tix	Si-N	S P, 350/200V, 4/6A, 100W, 25MHz, 600/1300ns		23a	TO-3	BUW 11 A	18j	BU 526, BUW 71, BUX 16C, BUY 67, ++
BD 253 A		Si-N	=BD 253: 500/250V		23a	TO-3	S 2530 A	23a	BU 526, BUS 11, BUX 45, BUX 82, ++
BD 253 B		Si-N	=BD 253: 700/300V		23a	TO-3	S 2530 A	23a	BU 526, BUS 11, BUX 82, BUX 97, ++
BD 253 C		Si-N	=BD 253: 900/400V		23a	TO-3	S 2530 A	23a	BU 526, BUS 11A, BUX 83, 2SD802, ++
BD 254	Tho	Si-N	LF P, 60V, 3A, 18,5W, 30MHz		22a	SOT-9	BD 243 C	17j	BD 241A, BD 243A, BD 535, BD 935, ++
BD 255	Tho	Si-P	LF P, 60V, 3A, 18,5W, 30MHz		22a	SOT-9	BD 244 C	17j	BD 242A, BD 244A, BD 536, BD 936, ++
BD 257/45...100	Aeg	Si-N	LF P, 45/45...100/100V, -/25A, 125W, >3MHz	BD258	18j	TO-3P	BD 249 C	18j	BD 249(A...C), 2SD1049, 2SD1841
BD 258/45...100	Aeg	Si-P	LF P, 45/45...100/100V, -/25A, 125W, >3MHz	BD257	18j	TO-3P	BD 250 C	18j	BD 250(A...C), 2SB1231
BD 260	Sgs	Si-N	LF,S P, 200/105V, 2A, 30W, >10MHz		22a	TO-66	2SD1138	17j	BUX 67, 2N3583, 2SC2023, 2SD610, 2SD760+
BD 261	Sgs	Si-N	LF,S P, 300/105V, 5A, 30W, >10MHz		22a	TO-66	BU 406	17j	BUX 63, MJE 51T, 2N6234...35, 2SC2907, ++
BD 262	Phi	Si-P-Darl	LF P, 60/60V, 4/6A, 36W, 7MHz, hFE>750	BD263	14h	TO-126	BD 680	14h	BD 678, BD 778, 2N6035
BD 262 A		Si-P-Darl	=BD 262: 80/80V		14h	TO-126	BD 680	14h	BD 680, BD 780, 2N6036
BD 262 B		Si-P-Darl	=BD 262: 100/100V		14h	TO-126			BD 682
BD 262 C		Si-P-Darl	=BD 262: 120/120V		14h	TO-126	BD 684	14h	BD 684
BD 262 L		Si-P-Darl	=BD 262: 45/45V		14h	TO-126	BD 680	14h	BD 678, BD 778, 2N6035
BD 263	Phi	Si-N-Darl	LF P, 80/60V, 4/6A, 36W, 7MHz, hFE>750	BD262	14h	TO-126	BD 679	14h	BD 679, BD 779, 2N6039

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BD 263 A		Si-N-Darl	=BD 263: 100/80V		14h	TO-126	BD 679	14h	BD 681
BD 263 B		Si-N-Darl	=BD 263: 120/100V		14h	TO-126	BD 683	14h	BD 683
BD 263 C		Si-N-Darl	=BD 263: 140/120V		14h	TO-126			-
BD 263 L		Si-N-Darl	=BD 263: 60/45V		14h	TO-126	BD 679	14h	BD 677, BD 777, 2N6038
BD 264	Phi	Si-P-Darl	LF P, 60/60V, 4/6A, 40W, 7MHz, hFE>1000	{BD265	17j	TO-220	BD 902	17j	BD 646, BD 898, BDW 24A, BDW 54A, ++
BD 264 A		Si-P-Darl	=BD 264: 80/80V		17j	TO-220	BD 902	17j	BD 648, BD 900, BDW 24B, BDW 54B, ++
BD 264 B		Si-P-Darl	=BD 264: 100/100V		17j	TO-220	BD 902	17j	BD 650, BD 902, BDW 24C, BDW 54C, ++
BD 264 L		Si-P-Darl	=BD 264: 45/45V		17j	TO-220	BD 902	17j	BD 644, BD 896, BDW 24, BDW 54, ++
BD 265	Phi	Si-N-Darl	LF P, 80/60V, 4/6A, 40W, 7MHz, hFE>1000	{BD264	17j	TO-220	BD 901	17j	BD 647, BD 899, BDW 23B, BDW 53B, ++
BD 265 A		Si-N-Darl	=BD 265: 100/80V		17j	TO-220	BD 901	17j	BD 649, BD 901, BDW 23C, BDW 53C, ++
BD 265 B		Si-N-Darl	=BD 265: 120/100V		17j	TO-220	BD 901	17j	BD 651, BDT 21, BDW 63D, 2SD1147
BD 265 L		Si-N-Darl	=BD 265: 60/45V		17j	TO-220	BD 901	17j	BD 645, BD 897, BDW 23A, BDW 53A, ++
BD 266	Phi	Si-P-Darl	LF P, 60/60V, 8/12A, 60W, 7MHz, hFE>750	{BD267	17j	TO-220	BD 902	17j	BD 646, BD 898, BDW 24A, BDW 64A, ++
BD 266 A		Si-P-Darl	=BD 266: 80/80V		17j	TO-220	BD 902	17j	BD 648, BD 900, BDW 24B, BDW 64B, ++
BD 266 B		Si-P-Darl	=BD 266: 100/100V		17j	TO-220	BD 902	17j	BD 650, BD 902, BDW 24C, BDW 64C, ++
BD 266 L		Si-P-Darl	=BD 266: 45/45V		17j	TO-220	BD 902	17j	BD 644, BD 896, BDW 24, BDW 64, ++
BD 267	Phi	Si-N-Darl	LF P, 80/60V, 8/12A, 60W, 7MHz, hFE>750	{BD266	17j	TO-220	BD 901	17j	BD 647, BD 899, BDW 23B, BDW 63B, ++
BD 267 A		Si-N-Darl	=BD 267: 100/80V		17j	TO-220	BD 901	17j	BD 649, BD 901, BDW 23C, BDW 63C, ++
BD 267 B		Si-N-Darl	=BD 267: 120/100V		17j	TO-220	BD 901	17j	BD 651, BDT 21, BDW 63D, 2SD1386
BD 267 L		Si-N-Darl	=BD 267: 60/45V		17j	TO-220	BD 901	17j	BD 645, BD 897, BDW 23A, BDW 63A, ++
BD 268	Phi	Si-P-Darl	LF P, 80/60V, 10A, 75W	{BD269	17j	TO-220	BDW 94 C	17j	BDT 62A, BDT 64A, BDW 94B, BDX 34B
BD 268 A		Si-P-Darl	=BD 268: 100/80V		17j	TO-220	BDW 94 C	17j	BDT 62B, BDT 64B, BDW 94C, BDX 34C
BD 269	Phi	Si-N-Darl	LF P, 80/60V, 10A, 75W	{BD268	17j	TO-220	BDW 93 C	17j	BDT 63A, BDT 65A, BDW 93B, BDX 33B
BD 269 A		Si-N-Darl	=BD 269: 100/80V		17j	TO-220	BDW 93 C	17j	BDT 63B, BDT 65B, BDW 93C, BDX 33C
BD 271	Phi	Si-N	LF P, 55/45V, 4/8A, 36W, >2MHz	{BD272	17j	TO-220	BD 243 C	17j	BD 243, BD 535, BD 539A, BD 949, 2SD960
BD 272	Phi	Si-P	LF P, 55/45V, 4/8A, 36W, >2MHz	{BD271	17j	TO-220	BD 244 C	17j	BD 244, BD 536, BD 540A, BD 950, 2SB868
BD 273	Phi	Si-N	=BD 271: 80/60V	{BD274	17j	TO-220	BD 243 C	17j	BD 243B, BD 537, BD 539B, BD 951, 2SD960
BD 274	Phi	Si-P	=BD 272: 80/60V	{BD273	17j	TO-220	BD 244 C	17j	BD 244B, BD 538, BD 540B, BD 951, 2SB868
BD 275	Phi	Si-N	=BD 271: 100/80V	{BD276	17j	TO-220	BD 243 C	17j	BD 243C, BD 539C, BD 953, 2SD712, 2SD960
BD 276	Phi	Si-P	=BD 272: 100/80V	{BD275	17j	TO-220	BD 244 C	17j	BD 244C, BD 540C, BD 954, 2SB682, 2SB868
BD 277	Phi,Rca	Si-P	LF,S P, 45/45V, 7A, 70W, >10MHz		17j	TO-220	BD 810	17j	BD 244, BD 544A, BD 796, BD 806, ++
BD 278(A,AE)	Phi	Si-N	LF,S P, 55/45V, 10A, 75W, >0,8MHz		17j	TO-220	BD 809	17j	BD 707, BD 805, BD 907, 2SD1062
BD 279	Gen	Si-N-Darl	LF P, -/40V, 2A, 10W, 75MHz, hFE>10000	{BD280	13j	TO-202			-
BD 280	Gen	Si-P-Darl	LF P, -/40V, 2A, 10W, 100MHz, hFE>10000		13j	TO-202			-
BD 281	Sgs	Si-N	P, 22/22V, 4/7A, 36W, >3MHz, sat<0,5V(3A)	{BD282	14h	TO-126	2SD1348	14h	BD 185, BD 433, 2N5190, 2SD1348
BD 282	Sgs	Si-P	P, 22/22V, 4/7A, 36W, >3MHz, sat<0,5V(3A)	{BD281	14h	TO-126	2SB986	14h	BD 186, BD 434, 2N5193, 2SB986
BD 283	Sgs	Si-N	=BD 281: 32/32V	{BD284	14h	TO-126	2SD1348	14h	BD 185, BD 435, 2N5190, 2SD1348
BD 284	Sgs	Si-P	=BD 282: 32/32V	{BD283	14h	TO-126	2SB986	14h	BD 186, BD 436, 2N5193, 2SB986
BD 285	Sgs	Si-N	=BD 281: 45/45V	{BD286	14h	TO-126	2SD1348	14h	BD 187, BD 437, 2N5191, 2SD1348
BD 286	Sgs	Si-P	=BD 282: 45/45V	{BD285	14h	TO-126	2SB986	14h	BD 188, BD 440, 2N5194, 2SB986
BD 287	Sie	Si-P	Strobo Flasher, 30/25V, 12A, 36W, >50MHz, <0,5/2µs		14h	TO-126			BD 487…488
BD 288	Sie	Si-P	=BD 287: 45/45V		14h	TO-126			BD 488
BD 289…290	Sie	Si							
BD 291	Phi	Si-N	LF P, 45/45V, 6/10A, 60W, >3MHz	{BD292	≈14j	SOT-82	(BD 243 C)[4]	17j	(BD 243, BD 543A, BD 795, BD 805)[4]
BD 292	Phi	Si-P	LF P, 45/45V, 6/10A, 60W, >3MHz	{BD291	≈14j	SOT-82	(BD 244 C)[4]	17j	(BD 244, BD 544A, BD 798, BD 806)[4]
BD 293	Phi	Si-N	=BD 291: 60/60V	{BD294	≈14j	SOT-82	(BD 243 C)[4]	17j	(BD 243A, BD 543A, BD 797, BD 807)[4]
BD 294	Phi	Si-P	=BD 292: 60/60V	{BD293	≈14j	SOT-82	(BD 244 C)[4]	17j	(BD 244A, BD 544A, BD 800, BD 808)[4]
BD 295	Phi	Si-N	=BD 291: 80/80V	{BD296	≈14j	SOT-82	(BD 243 C)[4]	17j	(BD 243B, BD 543B, BD 799, BD 809)[4]
BD 296	Phi	Si-P	=BD 292: 80/80V	{BD295	≈14j	SOT-82	(BD 244 C)[4]	17j	(BD 244B, BD 544B, BD 800, BD 810)[4]
BD 301	Tho	Si-N	LF P, TV-VA, 60/45V, 8/12A, 55W, >3MHz	{BD302	17j	TO-220	BD 809	17j	BD 543A, BD 709, BD 797, BD 807, 2SC3254
BD 302	Tho	Si-P	LF P, TV-VA, 60/45V, 8/12A, 55W, >3MHz	{BD301	17j	TO-220	BD 810	17j	BD 544A, BD 710, BD 798, BD 808, 2SA1290
BD 303	Tho	Si-N	LF P, TV-VA, 60/60V, 8/12A, 55W, >3MHz	{BD304	17j	TO-220	BD 809	17j	BD 543A, BD 707, BD 797, BD 807, 2SC3254
BD 303 A		Si-N	=BD 303: 80/80V		17j	TO-220	BD 809	17j	BD 543B, BD 709, BD 799, BD 809, 2SC3254
BD 303 B		Si-N	=BD 303: 100/100V		17j	TO-220			BD 543C, BD 711, BD 801, 2SC2527
BD 304	Tho	Si-P	LF P, TV-VA, 60/60V, 8/12A, 55W, >3MHz	{BD303	17j	TO-220	BD 810	17j	BD 544A, BD 708, BD 798, BD 806, 2SA1290
BD 304 A		Si-P	=BD 304: 80/80V		17j	TO-220	BD 810	17j	BD 544B, BD 710, BD 800, BD 810, 2SA1290
BD 304 B		Si-P	=BD 304: 100/100V		17j	TO-220			BD 544C, BD 712, BD 802, 2SA1077
BD 306(A,B)	Itt	Si-N	LF P, 36/36V, 2,5A, 10W, 100MHz		14h	TO-126	2SD1348	14h	BD 233, BD 785, 2SC2877, 2SD882, 2SD1348
BD 307(A,B)	Itt	Si-N	=BD 306: 64/64		14h	TO-126	2SD1348	14h	BD 235, BD 785, 2SD794(A), 2SD1818,++
BD 311	Mot,Phi	Si-N	LF P, 60/60V, 10/20A, 150W, >4MHz	{BD312	23a	TO-3	BD 317	23a	BD 315, BDW 21A, BDW 51A, 2N5877, ++
BD 312	Mot,Phi	Si-P	LF P, 60/60V, 10/20A, 150W, >3MHz	{BD311	23a	TO-3	BD 318	23a	BD 316, BDW 22A, BDW 52A, 2N5875, ++
BD 313	Mot,Phi	Si-N	=BD 311: 80/80V	{BD314	23a	TO-3	BD 317	23a	BD 315, BDW 21B, BDW 51B, 2N5878, ++
BD 314	Mot,Phi	Si-P	=BD 312: 80/80V	{BD313	23a	TO-3	BD 318	23a	BD 316, BDW 22B, BDW 52B, 2N5880, ++
BD 315	Mot	Si-N	LF P, 80/80V, 16/20A, 200W, >1MHz	{BD316	23a	TO-3	BD 317	23a	2N5629…5631
BD 316	Mot	Si-P	LF P, 80/80V, 16/20A, 200W, >1MHz	{BD315	23a	TO-3	BD 318	23a	2N6029…6031
BD 317	Mot	Si-N	=BD 315: 100/100V	{BD318	23a	TO-3	BD 317	23a	2N5629…5631
BD 318	Mot	Si-P	=BD 316: 100/100V	{BD317	23a	TO-3	BD 318	23a	2N6029…6031
BD 320(A,B,C)	Fer	Si-N-Darl	80/60V, 1A, 5W(Tc=25°), 80MHz, hFE>500		2a	TO-39	(BD 679)[4]	14h	BSS 51…52, (BD 877, BDX 43)[4]
BD 321(A,B,C)	Fer	Si-N-Darl	=BD 320: 2A		2a	TO-39	(BD 679)[4]	14h	2SC1888, 2SD406, 2SD614…615, 2SD688
BD 322(A,B,C)	Fer	Si-N-Darl	80/60V, 1A, 7,5W(Tc=25°), 80MHz, hFE>500		2a	TO-39	(BD 679)[4]	14h	BSS 51…52, (BD 877, BDX 43)[4]
BD 323(A,B,C)	Fer	Si-N-Darl	=BD 322: 2A		2a	TO-39	(BD 679)[4]	14h	2SC1888, 2SD406, 2SD614…615, 2SD688
BD 328	Fer	Si-N	5x Darl, 80/60V, 2A, 0,6W, 80MHz, hFE>1000		14-DIP	TO-116			-
BD 329	Phi,Sie	Si-N	P, 32/20V, 3A, 15W(Tc=45°), 130MHz, sat<0,5V(2A)		14h	TO-126	2SD882	14h	2SD882, 2SD1348, (BD 785, 2SD794(A))[17]
BD 330	Phi,Sie	Si-P	P, 32/20V, 3A, 15W(Tc=45°), 100MHz, sat<0,5V(2A)		14h	TO-126	2SB772	14h	2SB772, 2SB986, (BD 786, 2SB744(A))[17]
BD 331	Phi,Sgs	Si-N-Darl+Di	LF P, 60/60V, 6/10A, 60W, >10MHz, hFE>750	{BD332	≈14j	SOT-82	(BD 901)[4]	17j	(BD 645, BD 897, BDW 23A, BDW 63A, ++)[4]
BD 332	Phi,Sgs	Si-P-Darl+Di	LF P, 60/60V, 6/10A, 60W, >10MHz, hFE>750	{BD331	≈14j	SOT-82	(BD 902)[4]	17j	(BD 646, BD 898, BDW 24A, BDW 64A, ++)[4]
BD 333	Phi,Sgs	Si-N-Darl+Di	=BD 331: 80/80V	{BD334	≈14j	SOT-82	BD 901[4]	17j	(BD 647, BD 899, BDW 23B, BDW 63B, ++)[4]
BD 334	Phi,Sgs	Si-P-Darl+Di	=BD 332: 80/80V	{BD333	≈14j	SOT-82	BD 902[4]	17j	(BD 648, BD 900, BDW 24B, BDW 64B, ++)[4]
BD 335	Phi,Sgs	Si-N-Darl+Di	=BD 331: 100/100V	{BD336	≈14j	SOT-82	BD 901[4]	17j	(BD 649, BD 901, BDW 23C, BDW 63C, ++)[4]
BD 336	Phi,Sgs	Si-P-Darl+Di	=BD 332: 100/100V	{BD335	≈14j	SOT-82	BD 902[4]	17j	(BD 650, BD 902, BDW 24C, BDW 64C, ++)[4]
BD 337	Phi,Sgs	Si-N-Darl+Di	=BD 331: 120/120V	{BD338	≈14j	SOT-82			(BD 651, BDT 21, BDW 63D, BDW 74D, ++)[4]
BD 338	Phi,Sgs	Si-P-Darl+Di	=BD 332: 120/120V	{BD337	≈14j	SOT-82			(BD 652, BDT 20, BDW 64D, BDW 74D, ++)[4]
BD 342	Mot	Si-N	LF P, -/40V, 12/24A, 100W, 1,5MHz	{BD343	23a	TO-3	BD 317	23a	BD 249, BD 315, BDW 51A, 2N5881, ++
BD 343	Mot	Si-P	LF P, -/40V, 12/24V, 100W, 1,5MHz	{BD342	23a	TO-3	BD 318	23a	BD 250, BD 316, BDW 52A, 2N5879, ++
BD 344	Nsc	Si-P	LF P, 60/60V, 1A, 20W, >50MHz	{BD345	14h	TO-126	BD 140	14h	BD 138, BD 229, BD 378, BD 786, 2SA1220
BD 345	Nsc	Si-N	LF P, 60/60V, 1A, 20W, >50MHz	{BD344	14h	TO-126	BD 139	14h	BD 137, BD 228, BD 377, BD 785, 2SC2690
BD 346	Nsc	Si-P	LF P, 60/60V, 8A, 60W, >4MHz	{BD347	17j	TO-220	BD 810	17j	BD 544A, BD 708, BD 798, BD 808, ++
BD 347	Nsc	Si-N	LF P, 60/60V, 8A, 60W, >4MHz	{BD346	17j	TO-220	BD 809	17j	BD 543A, BD 707, BD 797, BD 807, ++
BD 348	Nsc	Si-P	LF P, 80/80V, 1A, 20W, >50MHz	{BD349	14h	TO-126	BD 140	14h	BD 140, BD 231, BD 380, BD 792, 2SA1220
BD 349	Nsc	Si-N	LF P, 80/80V, 1A, 20W, >50MHz	{BD348	14h	TO-126	BD 139	14h	BD 139, BD 230, BD 379, BD 791, 2SC2690
BD 350	Nsc	Si-P	LF P, -/80V, 15A, 160W, >4MHz	{BD351	23a	TO-3	BD 318	23a	BD 316, BD 318, 2N6029…6031
BD 350 A		Si-P	=BD 350: -/70V		23a	TO-3	BD 318	23a	BD 316, BD 318, 2N6029…6031
BD 350 B		Si-P	=BD 350: -/60V		23a	TO-3	BD 318	23a	BD 316, BD 318, 2N6029…6031

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BD 351	Nsc	Si-N	LF P, -/80V, 15A, 160W, >4MHz	{BD350	23a	TO-3	BD 317	23a	BD 315, BD 317, 2N5629…5631
BD 351 A		Si-N	=BD 351: -/70V		23a	TO-3	BD 317	23a	BD 315, BD 317, 2N5629…5631
BD 351 B		Si-N	=BD 351: -/60V		23a	TO-3	BD 317	23a	BD 315, BD 317, 2N5629…5631
BD 354(A,B,C)		Si-N	LF P, -/40V, 3A, 12,5W(Tc=45°), >30MHz	{BD355	22a	TO-66	(2SC1398)[7]	17j	MJE 15028, 2SC3252…3253
BD 355(A,B,C)		Si-P	LF P, -/40V, 3A, 12,5W(Tc=45°), >30MHz	{BD354	22a	TO-66	(2SA748)[7]	17j	MJE 15029, 2SA1288…1289
BD 356	Sie	Si-P	LF P, 20/20V, 5A, 20W, >50MHz	{BD357	14h	TO-126	2SA1357	14b	MJE 210, 2SA1120
BD 357	Sie	Si-N	LF P, 50/50V, 5A, 20W, >50MHz	{BD356	14h	TO-126	2SC3420	14b	MJE 200, 2SC2270, 2SD826
BD 358	Sie	Si-P	=BD 356: 8,3W	{BD359	13h	TO-202	(2SA1357)[4]	14b	(MJE 210, 2SA1120)[4]
BD 359	Sie	Si-N	=BD 357: 8,3W	{BD358	13h	TO-202	(2SC3420)[4]	14b	(MJE 200, 2SC2270, 2SD826)[4]
BD 361(A)	Mot	Si-N	LF P, 32/20V, 3A, 15W	{BD362	14h	TO-126	BD 189	14h	BD 175, BD 185, BD 435, 2N5190, 2SC2877+
BD 362(A)	Mot	Si-P	LF P, 32/20V, 3A, 15W	{BD361	14h	TO-126	BD 190	14h	BD 176, BD 186, BD 436, 2N5193, 2SA1217+
BD 363(A,B)	Sgs	Si-N	LF P, 60/40V, 6/10A, 75W		17j	TO-220	BD 809	17j	BD 243A, BD 543A, BD 797, BD 807, ++
BD 364	Mot	Si-N	LF P, 50/50V, 25A, 200W, >4MHz	{BD365	23a	TO-3			MJ 802, 2N5885
BD 365	Mot	Si-P	LF P, 50/50V, 25A, 200W, >4MHz	{BD364	23a	TO-3			MJ 4502, 2N5883
BD 366	Mot	Si-N	=BD 364: 60/60V	{BD367	23a	TO-3			MJ 802, 2N5885
BD 367	Mot	Si-P	=BD 365: 60/60V	{BD366	23a	TO-3			MJ 4502, 2N5883
BD 368	Mot	Si-N	=BD 364: 80/80V	{BD369	23a	TO-3			MJ 802, 2N5886
BD 369	Mot	Si-P	=BD 365: 80/80V	{BD368	23a	TO-3			MJ 4502, 2N5884
BD 370 A	Nsc	Si-P	LF Drv,Out, 45/45V, 1,5A, 2,5W, >50MHz	{BD371	30e	TO-237	(2SA1593)[5]	30j	(BD 518, BD 840, 2SB838…839, 2SB1201++)[4]
BD 370 B		Si-P	=BD 370A: 60/60		30e	TO-237	(2SA1593)[5]	30j	(BD 518, BD 842, 2SB839, 2SB1201,++)[4]
BD 370 C		Si-P	=BD 370A: 80/80V		30e	TO-237	(2SA1593)[5]	30j	(BD 520, BD 844, 2SB839, 2SB859,++)[4]
BD 370 D		Si-P	=BD 370A: 100/100V		30e	TO-237	(2SA1593)[5]	30j	(BD 530, BD 844, 2SB958, 2SA1593,++)[4]
BD 371 A	Nsc	Si-N	LF Drv,Out, 45/45V, 1,5A, 2,5W, >50MHz	{BD370	30e	TO-237	(2SC4135)[5]	30j	(BD 517, BD 839, 2SD1078…79, 2SD1282++)[4]
BD 371 B		Si-N	=BD 371A: 60/60V		30e	TO-237	(2SC4135)[5]	30j	(BD 517, BD 841, 2SD1079, 2SD1282,++)[4]
BD 371 C		Si-N	=BD 371A: 80/80V		30e	TO-237	(2SC4135)[5]	30j	(BD 519, BD 843, 2SD1079, 2SD1282,++)[4]
BD 371 D		Si-N	=BD 371A: 100/100V		30e	TO-237	(2SC4135)[5]	30j	(BD 529, BD 843, 2SD1282, 2SC4135,++)[4]
BD 372(A….D)	Nsc	Si-P	=BD 370A…D:	{BD373	30c	TO-237	›BD 370…		›BD 370A…D
BD 373(A….D)	Nsc	Si-N	=BD 371A…D:	{BD372	30c	TO-237	›BD 371…		›BD 371A…D
BD 375	Nsc,Sgs	Si-N	LF,S P, 50/45V, 2/3A, 25W, >50MHz, 75/500ns	{BD376	14h	TO-126	BD 237	14h	BD 177, BD 235, BD 785, 2SD1177…1178
BD 376	Nsc,Sgs	Si-P	LF,S P, 50/45V, 2/3A, 25W, >50MHz, 75/500ns	{BD375	14h	TO-126	BD 238	14h	BD 178, BD 236, BD 786, 2SB874…875
BD 377	Nsc,Sgs	Si-N	=BD 375: 75/60V	{BD378	14h	TO-126	BD 237	14h	BD 179, BD 237, BD 787, 2SD1177…1178
BD 378	Nsc,Sgs	Si-P	=BD 376: 75/60V	{BD377	14h	TO-126	BD 238	14h	BD 180, BD 238, BD 788, 2SB874…875
BD 379	Nsc,Sgs	Si-N	=BD 375: 100/80V	{BD380	14h	TO-126	BD 237	14h	BD 237, BD 791, 2SD1177…1178
BD 380	Nsc,Sgs	Si-P	=BD 376: 100/80V	{BD379	14h	TO-126	BD 238	14h	BD 238, BD 792, 2SB874…875
BD 385	Mot	Si-N	LF P, 60/60V, 1/2A, 10W, >350MHz	{BD386	13h	TO-202	(BD 139)[4]	14h	BD 827, BD 841
BD 386	Mot	Si-P	LF P, 60/60V, 1/2A, 10W, >350MHz	{BD385	13h	TO-202	(BD 140)[4]	14h	BD 828, BD 842
BD 387	Mot	Si-N	=BD 385: 80/80V	{BD388	13h	TO-202	(BD 139)[4]	14h	BD 829, BD 843
BD 388	Mot	Si-P	=BD 386: 80/80V	{BD387	13h	TO-202	(BD 140)[4]	14h	BD 830, BD 844
BD 389	Mot	Si-N	=BD 385: 100/100V	{BD390	13h	TO-202	(BD 139)[4]	14h	BD 829, BD 843
BD 390	Mot	Si-P	=BD 386: 100/100V	{BD389	13h	TO-202	(BD 140)[4]	14h	BD 830, BD 844
BD 400	Tix	Si-N	TV-VA, 170/100V, 1/3A, 20W, 65MHz		14h	TO-126	2SC3117	14h	2SC3117, 2SD669, (MJE 340)[7]
BD 401	Gen	Si-N	LF P, 60/45V, 10/20A, 50W, 50MHz	{BD402	17j	TO-220	BD 809	17j	BD 707, BD 743A, BD 807, BD 907, 2SC3255
BD 402	Gen	Si-P	LF P, 60/45V, 10/20A, 50W, 40MHz	{BD401	17j	TO-220	BD 810	17j	BD 708, BD 744A, BD 808, BD 908, 2SA1291
BD 403	Gen	Si-N	=BD 401: 60/60V	{BD404	17j	TO-220	BD 809	17j	BD 707, BD 743A, BD 807, BD 907, 2SC3255
BD 404	Gen	Si-P	=BD 402: 60/60V	{BD403	17j	TO-220	BD 810	17j	BD 708, BD 744A, BD 808, BD 908, 2SA1291
BD 410	Tix	Si-N	LF P, Vid P, 500/325V, 1/1,5A, 20W		14h	TO-126	(MJE 340)[7]	14h	BUV 93, 2SC3051, 2SC3425, 2SC3840
BD 411	Mot	Si-N-Darl	LF P, 50/40V, 2A, 10W, hFE=25k…150k	{BD413	13g	TO-202			MPS-U45
BD 412	Mot	Si-N-Darl	=BD 411: hFE=15k…150k	{BD414	13g	TO-202			MPS-U45
BD 413	Mot	Si-P-Darl	LF P, 50/40V, 2A, 10W, hFE=25k…150k	{BD411	13g	TO-202			MPS-U95
BD 414	Mot	Si-P-Darl	=BD 413: hFE=15k…150k	{BD412	13g	TO-202			MPS-U95
BD 415	Mot	Si-N	LF P, 60/60V, 1/2A, 10W, >75MHz	{BD416	13m	TO-202	(2SC4135)[4]	30j	BD 517, BD 525, (BD 385, BD 827)[5]
BD 416	Mot	Si-P	LF P, 60/60V, 1/2A, 10W, >75MHz	{BD415	13m	TO-202	(2SA1593)[4]	30j	BD 518, BD 526, (BD 386, BD 828)[5]
BD 417	Mot	Si-N	=BD 315: 80/80V	{BD418	13m	TO-202	(2SC4135)[4]	30j	BD 519, BD 527, (BD 387, BD 829)[5]
BD 418	Mot	Si-P	=BD 416: 80/80V	{BD417	13m	TO-202	(2SA1593)[4]	30j	BD 520, BD 528, (BD 388, BD 830)[5]
BD 419	Mot	Si-N	=BD 415: 100/100V	{BD420	13m	TO-202	(2SC4135)[4]	30j	BD 529, (BD 389, BD 829)[5]
BD 420	Mot	Si-P	=BD 416: 100/100V	{BD419	13m	TO-202	(2SA1593)[4]	30j	BD 530, (BD 390, BD 830)[5]
BD 421	Mot	Si-N-Darl	LF P, -/100V, -/2A, 10W, >100MHz, hFE>15k		13m	TO-202	(BD 679)[5]	14h	(BD 879, BDX 44)[5]
BD 422	Mot	Si-N-Darl	=BD 421: -/80V		13m	TO-202	(BD 679)[5]	14h	(BD 779, BD 877, BDX 43)[5]
BD 424	Sie	Si-N	TV-HA Drv, 160/100V, 0,8/1A, 2,5W(Tc=100°), 100MHz		13h	TO-202	2SC3117[4]	14h	BF 666…668, MJE 340, 2SC3117, (2SC2483)[5]
							MPS-U10[5]	13m	
BD 429	Sie	Si-N	LF P, 32/20V, 3A, 10W, 130MHz, sat<0,5V(2A)	{BD430	13h	TO-202	2SD1348	14h	BD329, BD785, 2SD1348, 2SD1506, 2SD1818+
BD 430	Sie	Si-P	LF P, 32/20V, 3A, 10W, 100MHz, sat<0,5V(2A)	{BD429	13h	TO-202	2SB986	14h	BD330, BD786, 2SB986, 2SB1065, 2SB1217++
BD 433	EUR	Si-N	LF P, 22/22V, 4/7A, 36W, >3MHz	{BD434	14h	TO-126	BD 189	14h	BD 185, 2N5190, 2SD1348
BD 434	EUR	Si-P	LF P, 22/22V, 4/7A, 36W, >3MHz	{BD433	14h	TO-126	BD 190	14h	BD 186, 2N5193, 2SB986
BD 435	EUR	Si-N	=BD 433: 32/32V	{BD436	14h	TO-126	BD 189	14h	BD 185, 2N5190, 2SD1348
BD 436	EUR	Si-P	=BD 434: 32/32V	{BD435	14h	TO-126	BD 190	14h	BD 186, 2N5193, 2SB986
BD 437	EUR	Si-N	=BD 433: 45/45V	{BD438	14h	TO-126	BD 189	14h	BD 187, 2N5191, 2SD1348
BD 438	EUR	Si-P	=BD 434: 45/45V	{BD437	14h	TO-126	BD 190	14h	BD 188, 2N5194, 2SB986
BD 439	EUR	Si-N	=BD 433: 60/60V	{BD440	14h	TO-126	BD 189	14h	BD 189, 2N5191, 2SD1348
BD 440	EUR	Si-P	=BD 434: 60/60V	{BD439	14h	TO-126	BD 190	14h	BD 190, 2N5194, 2SB986
BD 441	EUR	Si-N	=BD 433: 80/80V	{BD442	14h	TO-126	BD 189	14h	BD 189, 2N5192
BD 442	EUR	Si-P	=BD 434: 80/80V	{BD441	14h	TO-126	BD 190	14h	BD 190, 2N5195
BD 443	Mot	Si-N	LF,S P, 120/100V, 3A, 30W, >0,8MHz		14h	TO-126			-
BD 443 A		Si-N	=BD 443: 170/100V		14h	TO-126			-
BD 450	Rca	Si-N	LF P, 80/50V, 15A, 115W, >0,8MHz		23a	TO-3	BD 317	23a	BD 315, 2N5629…5631
BD 451	Rca	Si-N	=BD 450: 95/60V		23a	TO-3	BD 317	23a	BD 317, 2N5629…5631
BD 461	Tix	Si-N	LF P, 35/30V, 4/6A, 30W, hFE=80…320	{BD462	14h	TO-126	BD 189	14h	BD 185, BD 437, BD 785, 2N5190, 2SD1348
BD 462	Tix	Si-P	LF P, 35/30V, 4/6A, 30W, hFE=80…320	{BD461	14h	TO-126	BD 190	14h	BD 186, BD 438, BD 786, 2N5193, 2SB986
BD 463	Tix	Si-N	=BD 461: hFE=60…320	{BD464	14h	TO-126	BD 189	14h	BD 185, BD 437, BD 785, 2B5190, 2SD1348
BD 464	Tix	Si-P	=BD 462: hFE=60…320	{BD463	14h	TO-126	BD 190	14h	BD 186, BD 438, BD 786, 2N5193, 2SB986
BD 466 A	Tix	Si-P-Darl	LF P, 30/30V, 1A, 8,5W, 170MHz, hFE>8k	{BD477	14h	TO-126	(BD 680)[8]	14h	BD 876, BDX 45…47
BD 466 B		Si-P-Darl	=BD 466A: 45/45V		14h	TO-126	(BD 680)[8]	14h	BD 876, BDX 45…47
BD 477 A	Tix	Si-N-Darl	LF P, 30/30V, 1A, 8,5W, 170MHz, hFE>8k	{BD466	14h	TO-126	(BD 679)[8]	14h	BD 875, BDX 42…44
BD 477 B		Si-N-Darl	=BD 477A: 45/45V		14h	TO-126	(BD 679)[8]	14h	BD 875, BDX 42…44
BD 487	Tix	Si-P	Strobo, 30/25V, 12/15A, 12,5W, >50MHz, <0,5/2µs		13h	TO-202			BD 287…288
BD 488	Sie	Si-P	=BD 487: 45/45V		13h	TO-202			BD 288
BD 500	Rca	Si-P	LF P, 60/50V, 10A, 75W, >5MHz	{BD501	17j	TO-220	BD 810	17j	BD 708, BD 744A, BD 808, BD 908, 2SA1329
BD 500 A		Si-P	=BD 500: 70/60V		17j	TO-220	BD 810	17j	BD 710, BD 744A, BD 810, BD 910, 2SA1329
BD 500 B		Si-P	=BD 500: 90/80V		17j	TO-220	BD 810	17j	BD 712, BD 744B, BD 912
BD 501	Rca	Si-N	LF P, 60/50V, 10A, 75W, >5MHz	{BD500	17j	TO-220	BD 809	17j	BD 707, BD 743A, BD 807, BD 907, 2SC3346
BD 501 A		Si-N	=BD 501: 70/60V		17j	TO-220	BD 809	17j	BD 709, BD 743A, BD 809, BD 909, 2SC3346
BD 501 B		Si-N	=BD 501: 90/80V		17j	TO-220	BD 809	17j	BD 711, BD 743B, BD 911
BD 505	Mot	Si-N	LF Drv,Out, 30/20V, 2A, 10W, 250MHz	{BD506	13m	(Uniwatt)	(2SC4135)[4]	30j	BD 515, BD 525, (BD 839)[5]

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BD 506	Mot	Si-P	LF Drv,Out, 30/20V, 2A, 10W, 250MHz	{BD505	13m	(Uniwatt)	(2SA1593)[4]	30j	BD 516, BD 526, (BD 840)[5]
BD 507	Mot	Si-N	=BD 505: 40/30V	{BD508	13m	(Uniwatt)	(2SC4135)[4]	30j	BD 515, BD 525, (BD 839)[5]
BD 508	Mot	Si-P	=BD 506: 40/30V	{BD507	13m		(2SA1593)[4]	30j	BD 516, BD 526, (BD 840)[5]
BD 509	Mot	Si-N	=BD 505: 50/40V	{BD510	13m	(Uniwatt)	(2SC4135)[4]	30j	BD 517, BD 525, (BD 841)[5]
BD 510	Mot	Si-P	=BD 506: 60/50V	{BD509	13m	(Uniwatt)	(2SA1593)[4]	30j	BD 518, BD 526, (BD 842)[5]
BD 512	Itt	MOS-P-FET-e	VFET, LF P, 60/60V, 1,5A, 10W, on<7Ω, <10/10ns		13j	TO-202			-
BD 515	Mot	Si-N	LF Drv,Out, 45/45V, 2A, 10W, 160MHz	{BD516	13m	(Uniwatt)	(2SC4135)[4]	30j	BD 525, (BD 839)[5]
BD 516	Mot	Si-P	LF Drv,Out, 45/45V, 2A, 10W, 125MHz	{BD515	13m	(Uniwatt)	(2SA1593)[4]	30j	BD 526, (BD 840)[5]
BD 517	Mot	Si-N	=BD 515: 60/60V	{BD518	13m	(Uniwatt)	(2SC4135)[4]	30j	BD 525, (BD 841)[5]
BD 518	Mot	Si-P	=BD 516: 60/60V	{BD517	13m	(Uniwatt)	(2SA1593)[4]	30j	BD 526, (BD 842)[5]
BD 519	Mot	Si-N	=BD 515: 80/80V	{BD520	13m	(Uniwatt)	(2SC4135)[4]	30j	BD 527, (BD 843)[5]
BD 520	Mot	Si-P	=BD 516: 80/80V	{BD519	13m	(Uniwatt)	(2SA1593)[4]	30j	BD 528, (BD 844)[5]
BD 522	Itt	MOS-N-FET-e	VFET, LF P, 60/60V, 1,5A, 10W, on<3Ω, <10/10ns		13j	TO-202			-
BD 524	Sie	Si-N	TV-HA Drv, 160/100V, 0,8A, 5W, 100MHz		14h	TO-126	2SC3117	14h	2SC3051, 2SC3117, 2SC3425, 2SD669
BD 525	Mot	Si-N	LF Drv,Out, 60/60V, 2A, 10W, 150MHz	{BD526	13m	(Uniwatt)	(2SC4135)[4]	30j	BD 517, (BD 841)[5]
BD 526	Mot	Si-P	LF Drv,Out, 60/60V, 2A, 10W, 100MHz	{BD525	13m	(Uniwatt)	(2SA1593)[4]	30j	BD 518, (BD 842)[5]
BD 527	Mot	Si-N	=BD 525: 80/80V	{BD528	13m	(Uniwatt)	(2SC4135)[4]	30j	BD 519, (BD 843)[5]
BD 528	Mot	Si-P	=BD 526: 80/80V	{BD527	13m	(Uniwatt)	(2SA1593)[4]	30j	BD 518, (BD 844)[5]
BD 529	Mot	Si-N	=BD 525: 100/100V	{BD530	13m	(Uniwatt)	(2SC4135)[4]	30j	(BD 843)[5]
BD 530	Mot	Si-P	=BD 526: 100/100V	{BD529	13m	(Uniwatt)	(2SA1593)[4]	30j	(BD 844)[5]
BD 533(A)	Sie,Sgs,	Si-N	LF P, 45/45V, 4/8A, 50W, >3MHz	{BD534	17j	TO-220	BD 243 C	17j	BD 243, BD 539A, BD 543A, BD 947, ++
BD 534(A)	Sie,Sgs,++	Si-P	LF P, 45/45V, 4/8A, 50W, >3MHz	{BD533	17j	TO-220	BD 244 C	17j	BD 244, BD 540A, BD 544A, BD 950, ++
BD 535(A)	Sie,Sgs,++	Si-N	=BD 533: 60/60V	{BD536	17j	TO-220	BD 243 C	17j	BD 243A, BD 539A, BD 543A, BD 949, ++
BD 536(A)	Sie,Sgs,++	Si-P	=BD 534: 60/60V	{BD535	17j	TO-220	BD 244 C	17j	BD 244A, BD 540A, BD 544A, BD 950, ++
BD 537(A)	Sie,Sgs,++	Si-N	=BD 533: 80/80V	{BD538	17j	TO-220	BD 243 C	17j	BD 243B, BD 539B, BD 543B, BD 951, ++
BD 538(A)	Sie,Sgs,++	Si-P	=BD 534: 80/80V	{BD537	17j	TO-220	BD 244 C	17j	BD 244B, BD 540B, BD 544B, BD 952
BD 539	Tix	Si-N	LF P, 40/40V, 5A, 45W, >3MHz, 0,5/2µs	{BD540	17j	TO-220	BD 809	17j	BD 243, BD 543, BD 795, BD 805
BD 539 A		Si-N	=BD 539: 60/60V		17j	TO-220	BD 809	17j	BD 243A, BD 543A, BD 797, BD 807
BD 539 B		Si-N	=BD 539: 80/80V		17j	TO-220	BD 809	17j	BD 243B, BD 543B, BD 799, BD 809
BD 539 C		Si-N	=BD 539: 100/100V		17j	TO-220	BD 243 C	17j	BD 243C, BD 543C, BD 801, 2SD866
BD 539 D		Si-N	=BD 539: 120/120V		17j	TO-220	2SC2334	17j	BD 543D, 2SD866
BD 540	Tix	Si-P	LF P, 40/40V, 5A, 45W, >3MHz, 0,3/1µs	{BD539	17j	TO-220	BD 810	17j	BD 244, BD 544, BD 796, BD 806
BD 540 A		Si-P	=BD 540: 60/60V		17j	TO-220	BD 810	17j	BD 244A, BD 544A, BD 798, BD 808
BD 540 B		Si-P	=BD 540: 80/80V		17j	TO-220	BD 810	17j	BD 244B, BD 544B, BD 800, BD 810
BD 540 C		Si-P	=BD 540: 100/100V		17j	TO-220			BD 244C, BD 544C, BD 802, 2SB870
BD 540 D		Si-P	=BD 540: 120/120V		17j	TO-220			BD 544D, 2SB870
BD 543	Tix	Si-N	LF P, 40/40V, 8/10A, 70W, >3MHz, 0,6/1µs	{BD544	17j	TO-220	BD 809	17j	BD 705, BD 795, BD 805
BD 543 A		Si-N	=BD 543: 60/60V		17j	TO-220	BD 809	17j	BD 707, BD 797, BD 807
BD 543 B		Si-N	=BD 543: 80/80V		17j	TO-220	BD 809	17j	BD 709, BD 799, BD 809
BD 543 C		Si-N	=BD 543: 100/100V		17j	TO-220	2SC2334	17j	BD 711, BD 801, 2SD866
BD 543 D		Si-N	=BD 543: 120/120V		17j	TO-220	2SC2334	17j	2SD866
BD 544	Tix	Si-P	LF P, 40/40V, 8/10A, 70W, >3MHz, 0,4/0,7µs	{BD543	17j	TO-220	BD 810	17j	BD 706, BD 796, BD 806
BD 544 A		Si-P	=BD 544: 60/60V		17j	TO-220	BD 810	17j	BD 708, BD 798, BD 808
BD 544 B		Si-P	=BD 544: 80/80V		17j	TO-220	BD 810	17j	BD 710, BD 800, BD 810
BD 544 C		Si-P	=BD 544: 100/100V		17j	TO-220			BD 712, BD 802, 2SB870
BD 544 D		Si-P	=BD 544: 120/120V		17j	TO-220			2SB870
BD 545	Tix	Si-N	LF P, 40/40V, 15A, 85W, >3MHz, 0,6/1µs	{BD546	18j	TO-3P	BD 249 C	18j	BD 249, BD 745
BD 545 A		Si-N	=BD 545: 60/60V		18j	TO-3P	BD 249 C	18j	BD 249A, BD 745A
BD 545 B		Si-N	=BD 545: 80/80V		18j	TO-3P	BD 249 C	18j	BD 249B, BD 745B
BD 545 C		Si-N	=BD 545: 100/100V		18j	TO-3P	BD 249 C	18j	BD 249C, BD 745C
BD 545 D		Si-N	=BD 545: 120/120V		18j	TO-3P			BD 745D
BD 546	Tix	Si-P	LF P, 40/40V, 15A, 85W, >3MHz, 0,4/0,7µs	{BD545	18j	TO-3P	BD 250 C	18j	BD 250, BD 746
BD 546 A		Si-P	=BD 546: 60/60V		18j	TO-3P	BD 250 C	18j	BD 250A, BD 746A
BD 546 B		Si-P	=BD 546: 80/80V		18j	TO-3P	BD 250 C	18j	BD 250B, BD 746B
BD 546 C		Si-P	=BD 546: 100/100V		18j	TO-3P	BD 250 C	18j	BD 250C, BD 746C
BD 546 D		Si-P	=BD 546: 120/120V		18j	TO-3P			BD 746D
BD 550	Rca	Si-N	LF P, 130/110V, 7A, 150W, 5MHz		23a	TO-3	MJ 15015	23a	BDW 10...16, BUX 17, MJ 15015, 2SD665, ++
BD 550 A		Si-N	=BD 550: 200/175V		23a	TO-3	MJ 15015	23a	BDW 10, BUX 17, MJ 15015, 2SD665, ++
BD 550 B		Si-N	=BD 550: 275/250		23a	TO-3			BUX 17A, 2SD555, 2SD583, 2SC1586
BD 561	Mot	Si-N	LF P, 45/40V, 4A, 40W, >3MHz	{BD562	14h	TO-126	BD 189	14h	BD 187, BD 437, 2B5191, 2SD1348
BD 562	Mot	Si-P	LF P, 45/40V, 4A, 40W, >3MHz	{BD561	14h	TO-126	BD 190	14h	BD 188, BD 438, 2N5194, 2SB986
BD 566	Gen	Si-P-Darl	LF P, -/60V, 10A, 50W, hFE>1000	{BD567	17j	TO-220	BDW 94 C	17j	BDT 62A, BDT 64A, BDW 94B, BDX 34B
BD 566 A		Si-P-Darl	=BD 566: -/80V		17j	TO-220	BDW 94 C	17j	BDT 62B, BDT 64B, BDW 94C, BDX 34C
BD 567	Gen	Si-N-Darl	LF P, -/60V, 10A, 50W, hFE>1000	{BD566	17j	TO-220	BDW 93 C	17j	BDT 63A, BDT 65A, BDW 93B, BDX 33B
BD 567 A		Si-N-Darl	=BD 567: -/80V		17j	TO-220	BDW 93 C	17j	BDT 63B, BDT 65B, BDW 93C, BDX 33C
BD 575	Mot	Si-N	LF P, 45/45V, 3A, 40W, >3MHz	{BD576	15j	=TO-127	BD 243 C	17j	BD 585, BD 241, BD 533, BD 933, ++
BD 576	Mot	Si-P	LF P, 45/45V, 3A, 40W, >3MHz	{BD575	15j	=TO-127	BD 244 C	17j	BD 586, BD 242, BD 534, BD 934, ++
BD 577	Mot	Si-N	=BD 575: 60/60V	{BD578	15j	=TO-127	BD 243 C	17j	BD 587, BD 241A, BD 535, BD 935, ++
BD 578	Mot	Si-P	=BD 576: 60/60V	{BD577	15j	=TO-127	BD 244 C	17j	BD 588, BD 242A, BD 536, BD 936, ++
BD 579	Mot	Si-N	=BD 575: 80/80V	{BD580	15j	=TO-127	BD 243 C	17j	BD 589, BD 241B, BD 537, BD 937, ++
BD 580	Mot	Si-P	=BD 576: 80/80V	{BD579	15j	=TO-127	BD 244 C	17j	BD 590, BD 242B, BD 538, BD 938, ++
BD 581	Mot	Si-N	=BD 575: 100/100V	{BD582	15j	=TO-127	BD 243 C	17j	BD 591, BD 241C, BD 937, 2SD712, ++
BD 582	Mot	Si-P	=BD 576: 100/100V	{BD581	15j	=TO-127	BD 244 C	17j	BD 592, BD 242C, BD 938, 2SB682, ++
BD 585	Aeg,Mot	Si-N	LF P, 45/45V, 4/8A, 40W, >3MHz	{BD586	15j	=TO-127	BD 243 C	17j	BD 595, BD 533, BD 539, BD 947, ++
BD 586	Aeg,Mot	Si-P	LF P, 45/45V, 4/8A, 40W, >3MHz	{BD585	15j	=TO-127	BD 244 C	17j	BD 596, BD 534, BD 540, BD 948, ++
BD 587	Aeg,Mot	Si-N	=BD 585: 60/60V	{BD588	15j	=TO-127	BD 243 C	17j	BD 597, BD 535, BD 539A, BD 949, ++
BD 588	Aeg,Mot	Si-P	=BD 586: 60/60V	{BD587	15j	=TO-127	BD 244 C	17j	BD 598, BD 536, BD 540A, BD 950, ++
BD 589	Aeg,Mot	Si-N	=BD 585: 80/80V	{BD590	15j	=TO-127	BD 243 C	17j	BD 599, BD 537, BD 539B, BD 951, ++
BD 590	Aeg,Mot	Si-P	=BD 586: 80/80V	{BD589	15j	=TO-127	BD 244 C	17j	BD 600, BD 538, BD 540B, BD 952, ++
BD 591	Aeg,Mot	Si-N	=BD 585: 100/100V	{BD592	15j	=TO-127	BD 243 C	17j	BD 601, BD 539C, BD 953, 2SD712, ++
BD 592	Aeg,Mot	Si-P	=BD 586: 100/100V	{BD591	15j	=TO-127	BD 244 C	17j	BD 602, BD 540C, BD 954, 2SB682, ++
BD 595	Aeg,Mot	Si-N	LF P, 45/45V, 8/12A, 65W, >3MHz	{BD596	15j	=TO-127	BD 809	17j	BD 605, BD 543, BD 795, BD 805, ++
BD 596	Aeg,Mot	Si-P	LF P, 45/45V, 8/12A, 65W, >3MHz	{BD595	15j	=TO-127	BD 810	17j	BD 606, BD 544, BD 796, BD 806, ++
BD 597	Aeg,Mot	Si-N	=BD 595: 60/60V	{BD598	15j	=TO-127	BD 809	17j	BD 607, BD 543A, BD 797, BD 807, ++
BD 598	Aeg,Mot	Si-P	=BD 596: 60/60V	{BD597	15j	=TO-127	BD 810	17j	BD 608, BD 544A, BD 798, BD 808, ++
BD 599	Aeg,Mot	Si-N	=BD 595: 80/80V	{BD600	15j	=TO-127	BD 809	17j	BD 609, BD 543B, BD 799, BD 809, ++
BD 600	Aeg,Mot	Si-P	=BD 596: 80/80V	{BD599	15j	=TO-127	BD 810	17j	BD 610, BD 544B, BD 800, BD 810, ++
BD 601	Aeg,Mot	Si-N	=BD 595: 100/100V	{BD602	15j	=TO-127			BD 543C, BD 801, 2SD866
BD 602	Aeg,Mot	Si-P	=BD 596: 100/100V	{BD601	15j	=TO-127			BD 544C, BD 802, 2SB869
BD 605	Aeg,Mot	Si-N	LF P, 55/45V, 10A, 90W, >1,5MHz	{BD606	15j	=TO-127	BD 809	17j	BD 743A, BD 805, BD 907
BD 606	Aeg,Mot	Si-P	LF P, 55/45V, 10A, 90W, >1,5MHz	{BD605	15j	=TO-127	BD 810	17j	BD 744A, BD 806, BD 908
BD 607	Aeg,Mot	Si-N	=BD 605: 70/70V	{BD608	15j	=TO-127	BD 809	17j	BD 743A, BD 807, BD 909
BD 608	Aeg,Mot	Si-P	=BD 606: 70/60V	{BD607	15j	=TO-127	BD 810	17j	BD 744A, BD 808, BD 910

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BD 609	Aeg,Mot	Si-N	=BD 605: 80/80V	{BD610	15j	=TO-127	BD 809	17j	BD 743B, BD 809, BD 909
BD 610	Aeg,Mot	Si-P	=BD 606: 80V	{BD609	15j	=TO-127	BD 810	17j	BD 744B, BD 810, BD 910
BD 611	Sie	Si-N	LF P, 22/22V, 4/7A, 15W, >3MHz	{BD612	13h	TO-202	BD 189	14h	BD 185, BD 433, 2N5190, 2SD1348
BD 612	Sie	Si-P	LF P, 22/22V, 4/7A, 15W, >3MHz	{BD611	13h	TO-202	BD 190	14h	BD 186, BD 434, 2N5193, 2SB986
BD 613	Sie	Si-N	=BD 611: 32/32V	{BD614	13h	TO-202	BD 189	14h	BD 185, BD 435, 2N5190, 2SD1348
BD 614	Sie	Si-P	=BD 612: 32/32V	{BD613	13h	TO-202	BD 190	14h	BD 186, BD 436, 2N5193, 2SB986
BD 615	Sie	Si-N	=BD 611: 45/45V	{BD616	13h	TO-202	BD 189	14h	BD 187, BD 437, 2N5191, 2SD1348
BD 616	Sie	Si-P	=BD 612: 45/45V	{BD615	13h	TO-202	BD 190	14h	BD 188, BD 438, 2N5194, 2SB986
BD 617	Sie	Si-N	=BD 611: 60/60V	{BD618	13h	TO-202	BD 189	14h	BD 189, BD 439, 2N5191, 2SD1348
BD 618	Sie	Si-P	=BD 612: 60/60V	{BD617	13h	TO-202	BD 190	14h	BD 190, BD 440, 2N5194, 2SB986
BD 619	Sie	Si-N	=BD 611: 80/80V	{BD620	13h	TO-202	BD 189	14h	BD 441, 2N5192
BD 620	Sie	Si-P	=BD 612: 80/80V	{BD619	13h	TO-202	BD 190	14h	BD 442, 2N5195
BD 633	Tix,Mic	Si-N	LF P, 45/45V, 2/5A, 30W, >3MHz	{BD634	17j	TO-220	BD 243 C	17j	BD 239, BD 241, BD 533, BD 933, 2SC1398+
BD 634	Tix,Mic	Si-P	LF P, 45/45V, 2/5A, 30W, >3MHz	{BD633	17j	TO-220	BD 244 C	17j	BD 240, BD 242, BD 534, BD 934, 2SA748++
BD 635	Tix,Mic	Si-N	=BD 633: 60/60V	{BD636	17j	TO-220	BD 243 C	17j	BD239A, BD241A, BD535, BD935, 2SC1398,++
BD 636	Tix,Mic	Si-P	=BD 634: 60/60V	{BD635	17j	TO-220	BD 244 C	17j	BD240A, BD242A, BD536, BD936, 2SA748,++
BD 637	Tix,Mic	Si-N	=BD 633: 100/80V	{BD638	17j	TO-220	BD 243 C	17j	BD239C, BD241C, BD937, 2SD712, 2SC2528++
BD 638	Tix,Mic	Si-P	=BD 634: 100/100V	{BD637	17j	TO-220	BD 244 C	17j	BD240C, BD242C, BD938, 2SB682, 2SA1078++
BD 643	EUR	Si-N-Darl+Di	LF P, 60/45V, 8/12A, 62,5W, >10MHz, hFE>750	{BD644	17j	TO-220	BD 901	17j	BD 895, BDW 73, BDX 33, BDX 53, ++
BD 643 F	Phi	Si-N-Darl+Di	=BD 643: Iso, >20W		17c	SOT-186	2SD1415	17c	BDT 63(A…C)F, 2SD1415…17, 2SD1826, ++
BD 644	EUR	Si-P-Darl+Di	LF P, 45/45V, 8/12A, 62,5W, >10MHz, hFE>750	{BD643	17j	TO-220	BD 902	17j	BD 896, BDW 74, BDX 34, BDX 54, ++
BD 644 F	Phi	Si-P-Darl+Di	=BD 644: Iso, >20W		17c	SOT-186	2SB1020	17c	BDT 62(A…C)F, 2SB1020…22, 2SB1224, ++
BD 645	EUR	Si-N-Darl+Di	=BD 643: 80/60V	{BD646	17j	TO-220	BD 901	17j	BD 897, BDW 73A, BDX 33A, BDX 53A, ++
BD 645 F	Phi	Si-N-Darl+Di	=BD 645: Iso, >20W		17c	SOT-186	2SD1415	17c	BDT 63AF…CF, 2SD1415…16, 2SD1791, ++
BD 646	EUR	Si-P-Darl+Di	=BD 644: 60/60V	{BD645	17j	TO-220	BD 902	17j	BD 898, BDW 74A, BDX 34A, BDX 54A, ++
BD 646 F	Phi	Si-P-Darl+Di	=BD 646: Iso, >20W		17c	SOT-186	2SB1020	17c	BDT 62(A…C)F, 2SB1020…22, 2SB1224, ++
BD 647	EUR	Si-N-Darl+Di	=BD 643: 100/80V	{BD648	17j	TO-220	BD 901	17j	BD 899, BDW 73B, BDX 33B, BDX 53B, ++
BD 647 F	Phi	Si-N-Darl+Di	=BD 647: Iso, >20W		17c	SOT-186	2SD1415	17c	BDT 63BF…CF, 2SD1415, 2SD1791, ++
BD 648	EUR	Si-P-Darl+Di	=BD 644: 80/80V	{BD647	17j	TO-220	BD 902	17j	BD 900, BDW 74B, BDX 34B, BDX 54B, ++
BD 648 F	Phi	Si-P-Darl+Di	=BD 648: Iso, >20W		17c	SOT-186	2SB1020	17c	BDT 62AF…CF, 2SB1020…21, 2SB1283, ++
BD 649	EUR	Si-N-Darl+Di	=BD 643: 120/100V	{BD650	17j	TO-220			BD 901, BDW 73C, BDX 33C, BDX 53C, ++
BD 649 F	Phi	Si-N-Darl+Di	=BD 649: Iso, >20W		17c	SOT-186			BDT 63CF, 2SD1590, 2SD1792, 2SD1590, ++
BD 650	EUR	Si-P-Darl+Di	=BD 644: 100/100V	{BD649	17j	TO-220	BD 902	17j	BD 902, BDW 74C, BDX 34C, BDX 54C, ++
BD 650 F	Phi	Si-P-Darl+Di	=BD 650: Iso, >20W		17c	SOT-186	2SB1020	17c	BDT 62AF…CF, 2SB1020, 2SB1283, ++
BD 651	EUR	Si-N-Darl+Di	=BD 643: 140/120V	{BD652	17j	TO-220			BDW 73D, BDX 33D, BDX 53E, BDT 21, ++
BD 651 F	Phi	Si-N-Darl+Di	=BD 651: Iso, >20W		17c	SOT-186			2SD1590, 2SD1792
BD 652	EUR	Si-P-Darl+Di	=BD 644: 120/120V	{BD651	17j	TO-220			BDW 74D, BDX 34D, BDX 54E, BDT 20, ++
BD 652 F	Phi	Si-P-Darl+Di	=BD 652: Iso, >20W		17c	SOT-186			BDT 62CF, 2SB1344
BD 661	Sgs	Si-N	LF P, 32/32V, 4A, 36W	{BD662	≈14j	SOT-82	(BD 243 C)[4]	17j	(BD 243, BD 533, BD 539, 945, ++)[4]
BD 661 K		Si-N	=BD 661: 50W		17j	TO-220	BD 243 C	17j	BD 243, BD 533, BD 539, BD 945, ++
BD 662	Sgs	Si-P	LF P, 32/32V, 4A, 32W	{BD661	≈14j	SOT-82	(BD 244 C)[4]	17j	(BD 244, BD 534, BD 540, BD 946, ++)[4]
BD 662 K		Si-P	=BD 662: 50W		17j	TO-220	BD 244 C	17j	BD 244, BD 534, BD 540, BD 946, ++
BD 663(A,B)	Sgs	Si-N	LF P, 45/45V, 10A, 75W, >3MHz	{BD664	17j	TO-220	BD 809	17j	BD 705, BD 743, BD 805, BD 905
BD 664(A,B)	Sgs	Si-P	LF P, 45/45V, 10A, 75W, >3MHz	{BD663	17j	TO-220	BD 810	17j	BD 706, BD 744, BD 806, BD 906
BD 675(A)	EUR	Si-N-Darl+Di	LF P, 45/45V, 4/7A, 40W, >10MHz, hFE>750	{BD676	14h	TO-126	BD 679	14h	BD 775, 2N6038
BD 676(A)	EUR	Si-P-Darl+Di	LF P, 45/45V, 4/7A, 40W, >10MHz, hFE>750	{BD675	14h	TO-126	BD 680	14h	BD 776, 2N6035
BD 677(A)	EUR	Si-N-Darl+Di	=BD 675: 60/60V	{BD678	14h	TO-126	BD 679	14h	BD 777, 2N6038
BD 678(A)	EUR	Si-P-Darl+Di	=BD 676: 60/60V	{BD677	14h	TO-126	BD 680	14h	BD 778, 2N6035
BD 679(A)	EUR	Si-N-Darl+Di	=BD 675: 80/80V	{BD680	14h	TO-126	BD 679	14h	BD 779, 2N6039
BD 680(A)	EUR	Si-P-Darl+Di	=BD 676: 80/80V	{BD679	14h	TO-126	BD 680	14h	BD 780, 2N6036
BD 681	EUR	Si-N-Darl+Di	=BD 675: 100/100V	{BD682	14h	TO-126	BD 683	14h	-
BD 682	EUR	Si-P-Darl+Di	=BD 676: 100/100V	{BD681	14h	TO-126	BD 684	14h	-
BD 683	Phi	Si-N-Darl+Di	=BD 675: 140/120V	{BD684	14h	TO-126	BD 683	14h	-
BD 684	Phi	Si-P-Darl+Di	=BD 676: 120/120V	{BD683	14h	TO-126	BD 684	14h	-
BD 675H….680H	Sgs	Si-N/P-Darl	=BD 675…680:		≈14j	SOT-82	(BD 901/902)[4]	17j	(=BD 675…680)[5]
BD 695(A)	Aeg,Mot	Si-N-Darl	LF P, 45/45V, 8A, 70W, >1MHz, hFE>750	{BD696	15j	=TO-127	BD 901	17j	BD 643, BD 895, BDW 73, BDX 53, ++
BD 696(A)	Aeg,Mot	Si-P-Darl	LF P, 45/45V, 8A, 70W, >1MHz, hFE>750	{BD695	15j	=TO-127	BD 902	17j	BD 644, BD 896, BDW 74, BDX 54, ++
BD 697(A)	Aeg,Mot	Si-N-Darl	=BD 695: 60/60V	{BD698	15j	=TO-127	BD 901	17j	BD 645, BD 897, BDW 73A, BDX 53A, ++
BD 698(A)	Aeg,Mot	Si-P-Darl	=BD 696: 60/60V	{BD697	15j	=TO-127	BD 902	17j	BD 646, BD 898, BDW 74A, BDX 54A, ++
BD 699(A)	Aeg,Mot	Si-N-Darl	=BD 695: 80/80V	{BD700	15j	=TO-127	BD 901	17j	BD 647, BD 899, BDW 73B, BDX 53B, ++
BD 700(A)	Aeg,Mot	Si-P-Darl	=BD 696: 80/80V	{BD699	15j	=TO-127	BD 902	17j	BD 648, BD 900, BDW 74B, BDX 54B, ++
BD 701	Aeg,Mot	Si-N-Darl	=BD 695: 100/100V	{BD702	15j	=TO-127	BD 901	17j	BD 649, BD 901, BDW 73C, BDX 53C, ++
BD 702	Aeg,Mot	Si-P-Darl	=BD 696: 100/100V	{BD701	15j	=TO-127	BD 902	17j	BD 650, BD 902, BDW 74C, BDX 54C, ++
BD 705	Tho	Si-N	LF P, 45/45V, 12A, 75W, >3MHz	{BD706	17j	TO-220	BD 809	17j	BD 743, BD 905
BD 706	Tho	Si-P	LF P, 45/45V, 12A, 75W, >3MHz	{BD705	17j	TO-220	BD 810	17j	BD 744, BD 906
BD 707	Tho	Si-N	=BD 705: 60/60V	{BD708	17j	TO-220	BD 809	17j	BD 743A, BD 907
BD 708	Tho	Si-P	=BD 706: 60/60V	{BD707	17j	TO-220	BD 810	17j	BD 744A, BD 908
BD 709	Tho	Si-N	=BD 705: 80/80V	{BD710	17j	TO-220	BD 809	17j	BD 743B, BD 909
BD 710	Tho	Si-P	=BD 706: 80/80V	{BD709	17j	TO-220	BD 810	17j	BD 744B, BD 910
BD 711	Tho	Si-N	=BD 705: 100/100V	{BD712	17j	TO-220			BD 743C, BD 911
BD 712	Tho	Si-P	=BD 706: 100/100V	{BD711	17j	TO-220			BD 744C, BD 912
BD 713	Sie	Si-N-Darl	LF P, 45/45V, 4A, 36W, >1MHz, hFE>750	{BD714	17j	TO-220	BD 901	17j	BD 643, BD 895, BDW 23, BDW 53, ++
BD 714	Sie	Si-P-Darl	LF P, 45/45V, 4A, 36W, >1MHz, hFE>750	{BD713	17j	TO-220	BD 902	17j	BD 644, BD 896, BDW 24, BDW 54, ++
BD 715	Sie	Si-N-Darl	=BD 713: 60/60V	{BD716	17j	TO-220	BD 901	17j	BD 645, BD 897, BDW 23A, BDW 53A, ++
BD 716	Sie	Si-P-Darl	=BD 714: 60/60V	{BD715	17j	TO-220	BD 902	17j	BD 646, BD 898, BDW 24A, BDW 54A, ++
BD 717	Sie	Si-N-Darl	=BD 713: 80/80V	{BD718	17j	TO-220	BD 901	17j	BD 647, BD 899, BDW 23B, BDW 53B, ++
BD 718	Sie	Si-P-Darl	=BD 713: 80/80V	{BD717	17j	TO-220	BD 902	17j	BD 648, BD 900, BDW 24B, BDW 54B, ++
BD 719	Phi	Si-N	LF,S P, 60/60V, 4/7A, 36W, >3MHz, 300/1500ns	{BD720	14h	TO-126	BD 189	14h	BD 189, BD 439, BD 441, 2N5191…92
BD 720	Phi	Si-P	LF,S P, 60/60V, 4/7A, 36W, >3MHz, 100/400ns	{BD719	14h	TO-126	BD 190	14h	BD 190, BD 440, BD 442, 2N5194…95
BD 721	Phi	Si-N	=BD 719: 80/80V	{BD722	14h	TO-126	(BD 189)[7]	14h	BD 441, 2N5192
BD 722	Phi	Si-P	=BD 720: 80/80V	{BD721	14h	TO-126	(BD 190)[7]	14h	BD 442, 2N5195
BD 723	Phi	Si-N	=BD 719: 100/100V	{BD724	14h	TO-126			-
BD 724	Phi	Si-P	=BD 720: 100/100V	{BD723	14h	TO-126			-
BD 725	Phi	Si-N	=BD 719: 120/120V	{BD726	14h	TO-126			-
BD 726	Phi	Si-P	=BD 720: 120/120V	{BD725	14h	TO-126			-
BD 733	Nsc,Tix	Si-N	LF P, 25/25V, 4/7A, 40W, >3MHz	{BD734	17j	TO-220	BD 243 C	17j	BD 243, BD 533, BD 539, BD 943, ++
BD 734	Nsc,Tix	Si-P	LF P, 25/25V, 4/7A, 40W, >3MHz	{BD733	17j	TO-220	BD 244 C	17j	BD 244, BD 534, BD 540, BD 944, ++
BD 735	Nsc,Tix	Si-N	=BD 733: 35/35V	{BD736	17j	TO-220	BD 243 C	17j	BD 243, BD 533, BD 539, BD 947, ++
BD 736	Nsc,Tix	Si-P	=BD 734: 35/35V	{BD735	17j	TO-220	BD 244 C	17j	BD 244, BD 534, BD 540, BD 948, ++
BD 737	Nsc,Tix	Si-N	=BD 733: 45/45V	{BD738	17j	TO-220	BD 243 C	17j	BD 243, BD 533, BD 539A, BD 947, ++
BD 738	Nsc,Tix	Si-P	=BD 734: 45/45V	{BD737	17j	TO-220	BD 244 C	17j	BD 244, BD 534, BD 540A, BD 948, ++
BD 743	Tix	Si-N	LF P, 50/45V, 15/20A, 90W, >5MHz, 370/900ns	{BD744	17j	TO-220			BD 907, BDT 81
BD 743 A		Si-N	=BD 743: 70/60		17j	TO-220			BD 909, BDT 83

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BD 743 B		Si-N	=BD 743: 90/80V		17j	TO-220			BD 911, BDT 85
BD 743 C		Si-N	=BD 743: 110/100V		17j	TO-220			BDT 87
BD 743 D		Si-N	=BD 743: 130/120V		17j	TO-220			-
BD 743 E		Si-N	=BD 743: 150/140V		17j	TO-220			-
BD 743 F		Si-N	=BD 743: 170/160V		17j	TO-220			-
BD 744	Tix	Si-P	LF P, 50/45V, 15/20A, 90W, >5MHz, 140/900ns	{BD743	17j	TO-220			BD 908, BDT 82
BD 744 A		Si-P	=BD 744: 70/60V		17j	TO-220			BD 910, BDT 84
BD 744 B		Si-P	=BD 744: 90/80V		17j	TO-220			BD 912, BDT 86
BD 744 C		Si-P	=BD 744: 110/100V		17j	TO-220			BDT 88
BD 744 D		Si-P	=BD 744: 130/120V		17j	TO-220			-
BD 744 E		Si-P	=BD 744: 150/140V		17j	TO-220			-
BD 744 F		Si-P	=BD 744: 170/160V		17j	TO-220			-
BD 745	Tix	Si-N	LF P, 50/45V, 20/25A, 115W, >5MHz, 370/900ns	{BD746	18j	TO-3P	BD 249 C	18j	BD 249, 2SD1049, 2SD1841
BD 745 A		Si-N	=BD 745: 70/60V		18j	TO-3P	BD 249 C	18j	BD 249A, 2SD1049, 2SD1841
BD 745 B		Si-N	=BD 745: 90/80V		18j	TO-3P	BD 249 C	18j	BD 249B, 2SD1049, 2SD1841
BD 745 C		Si-N	=BD 745: 110/100V		18j	TO-3P	BD 249 C	18j	BD 249C, 2SD1049, 2SD1841
BD 745 D		Si-N	=BD 745: 130/120V		18j	TO-3P			BD 249D
BD 745 E		Si-N	=BD 745: 150/140V		18j	TO-3P			BD 249D
BD 745 F		Si-N	=BD 745: 170/160V		18j	TO-3P			BD 249E
BD 746	Tix	Si-P	LF P, 50/45V, 20/25A, 115W, >5MHz, 140/900ns	{BD745	18j	TO-3P	BD 250 C	18j	BD 250, 2SB1231
BD 746 A		Si-P	=BD 746: 70/60V		18j	TO-3P	BD 250 C	18j	BD 250A, 2SB1231
BD 746 B		Si-P	=BD 746: 90/80V		18j	TO-3P	BD 250 C	18j	BD 250B, 2SB1231
BD 746 C		Si-P	=BD 746: 110/100V		18j	TO-3P	BD 250 C	18j	BD 250C, 2SB1231
BD 746 D		Si-P	=BD 746: 130/120V		18j	TO-3P			BD 250D
BD 746 E		Si-P	=BD 746: 150/140V		18j	TO-3P			BD 250D
BD 746 F		Si-P	=BD 746: 170/160V		18j	TO-3P			BD 250E
BD 750	Rca	Si-P	LF P, 100/90V, -/20A, 200W, >4MHz	{BD751	23a	TO-3	BD 318	23a	BD 318, 2N6029…6031, 2SA1117
BD 750 A		Si-P	=BD 750: 130/120V		23a	TO-3	MJ 15016	23a	2N6030…6031, MJ 15016, 2SA1117
BD 750 B		Si-P	=BD 750: 110/100V, 250W		23a	TO-3			-
BD 750 C		Si-P	=BD 750: 140/130V, 250W		23a	TO-3			-
BD 751	Rca	Si-N	LF P, 100/90V, -/20A, 200W, >4MHz	{BD750	23a	TO-3	BD 317	23a	BD 317, 2N5629…5631, 2SC2608
BD 751 A		Si-N	=BD 751: 130/120V		23a	TO-3	MJ 15015	23a	MJ 15015, 2N5630…5631, 2SC2608
BD 751 B		Si-N	=BD 751: 110/100V, 250W		23a	TO-3			-
BD 751 C		Si-N	=BD 751: 140/130V, 250W		23a	TO-3			-
BD 775	Mot	Si-N-Darl	45/45V, 4/6A, 15W,>20MHz, hFE>750, 250/600ns	{BD776	14h	TO-126	BD 679	14h	BD 675, 2N6038
BD 776	Mot	Si-P-Darl	45/45V, 4/6A, 15W,>20MHz, hFE>750, 150/400ns	{BD775	14h	TO-126	BD 680	14h	BD 676, 2N6035
BD 777	Mot	Si-N-Darl	=BD 775: 60/60V	{BD778	14h	TO-126	BD 679	14h	BD 677, 2N6038
BD 778	Mot	Si-P-Darl	=BD 776: 60/60V	{BD777	14h	TO-126	BD 680	14h	BD 678, 2N6035
BD 779	Mot	Si-N-Darl	=BD 775: 80/80V	{BD780	14h	TO-126	BD 679	14h	BD 679, 2N6039
BD 780	Mot	Si-P-Darl	=BD 776: 80/80V	{BD779	14h	TO-126	BD 680	14h	BD 680, 2N6036
BD 785	Mot	Si-N	LF P, 60/45V, 4/8A, 15W, >50MHz	{BD786	14h	TO-126	2SD1348	14h	BDX 35…37, MJE 240…244, 2SD1348
BD 786	Mot	Si-P	LF P, 60/45V, 4/8A, 15W, >50MHz	{BD785	14h	TO-126	2SB986	14h	MJE 250…254, 2SB986
BD 787	Mot	Si-N	=BD 785: 80/60V	{BD788	14h	TO-126	(BD 189)[8]	14h	BDX 35…37, MJE 240…244
BD 788	Mot	Si-P	=BD 786: 80/60V	{BD787	14h	TO-126	(BD 190)[8]	14h	MJE 250…254
BD 789	Mot	Si-N	=BD 785: 80/80V	{BD790	14h	TO-126	(BD 189)[8]	14h	BDX 35…37, MJE 240…244
BD 790	Mot	Si-P	=BD 786: 80/80V	{BD789	14h	TO-126	(BD 190)[8]	14h	MJE 250…254
BD 791	Mot	Si-N	=BD 785: 100/100V	{BD792	14h	TO-126			BDX 35…37, MJE 240…244
BD 792	Mot	Si-P	=BD 786: 100/100V	{BD791	14h	TO-126			MJE 250…254
BD 795	Mot,Rca	Si-N	LF P, 45/45V, 8A, 65W, >3MHz	{BD796	17j	TO-220	BD 809	17j	BD 543A, BD 705, BD 805, 2SD866
BD 796	Mot,Rca	Si-P	LF P, 45/45V, 8A, 65W, >3MHz	{BD795	17j	TO-220	BD 810	17j	BD 544A, BD 706, BD 806, 2SB870
BD 797	Mot,Rca	Si-N	=BD 795: 60/60V	{BD798	17j	TO-220	BD 809	17j	BD 543A, BD 707, BD 807, 2SD866
BD 798	Mot,Rca	Si-P	=BD 796: 60/60V	{BD797	17j	TO-220	BD 810	17j	BD 544A, BD 708, BD 808, 2SB870
BD 799	Mot,Rca	Si-N	=BD 795: 80/80V	{BD800	17j	TO-220	BD 809	17j	BD 543B, BD 709, BD 809, 2SD866
BD 800	Mot,Rca	Si-P	=BD 796: 80/80V	{BD799	17j	TO-220	BD 810	17j	BD 544B, BD 710, BD 810, 2SB870
BD 801	Mot,Rca	Si-N	=BD 795: 100/100V	{BD802	17j	TO-220			BD 543C, BD 711, 2SD866
BD 802	Mot,Rca	Si-P	=BD 796: 100V		17j	TO-220			BD 544C, BD 712, 2SB870
BD 805	Mot	Si-N	LF P, 55/45V, 10A, 90W, >1,5MHz	{BD806	17j	TO-220	BD 809	17j	BD 707, BD 743A, BD 907, BDT 95
BD 806	Mot	Si-P	LF P, 55/45V, 10A, 90W, >1,5MHz	{BD805	17j	TO-220	BD 810	17j	BD 708, BD 744A, BD 908, BDT 96
BD 807	Mot	Si-N	=BD 805: 70/60V	{BD808	17j	TO-220	BD 809	17j	BD 709, BD 743A, BD 909, BDT 95
BD 808	Mot	Si-P	=BD 806: 70/60V	{BD807	17j	TO-220	BD 810	17j	BD 710, BD 744A, BD 910, BDT 96
BD 809	Mot	Si-N	=BD 805: 80/80V	{BD810	17j	TO-220	BD 809	17j	BD 709, BD 743B, BD 909, BDT 95
BD 810	Mot	Si-P	=BD 806: 80/80V	{BD809	17j	TO-220	BD 810	17j	BD 710, BD 744B, BD 910, BDT 96
BD 813(A)	Aeg,Phi	Si-N	LF P, 45/45V, 2/6A, 12,5W, >3MHz, 400/1500ns	{BD814	13h	TO-202	BD 237	14h	BD 175, BD 233, BD 615, 2SD1177…78
BD 814(A)	Aeg,Phi	Si-P	LF P, 45/45V, 2/6A, 12,5W, >3MHz, 300/700ns	{BD813	13h	TO-202	BD 238	14h	BD 176, BD 234, BD 616, 2SB874…75
BD 815(A)	Aeg,Phi	Si-N	=BD 813: 60/60V	{BD816	13h	TO-202	BD 237	14h	BD 177, BD 235, BD 617, 2SD1177…78
BD 816(A)	Aeg,Phi	Si-P	=BD 814: 60/60V	{BD815	13h	TO-202	BD 238	14h	BD 178, BD 236, BD 618, 2SB874…75
BD 817(A)	Aeg,Phi	Si-N	=BD 813: 100/80V	{BD818	13h	TO-202	BD 237	14h	BD 237, BD 443, 2SD1177…78
BD 818(A)	Aeg,Phi	Si-P	=BD 814: 100/80V	{BD817	13h	TO-202	BD 238	14h	BD 238, 2SB874…75
BD 819…822A…C	Phi	Si							
BD 825(A,B)	Aeg,Phi,++	Si-N	LF P, 45/45V, 1/1,5A, 8W, 250MHz	{BD826	13h	TO-202	BD 139	14h	BD 135, BD 226, BD 385, BD 839, 2SC2690
BD 826(A,B)	Aeg,Phi,++	Si-P	LF P, 45/45V, 1/1,5A, 8W, 75MHz	{BD825	13h	TO-202	BD 140	14h	BD 136, BD 227, BD 386, BD 840, 2SA1220
BD 827(A,B)	Aeg,Phi,++	Si-N	=BD 825: 60/60V	{BD828	13h	TO-202	BD 139	14h	BD 137, BD 228, BD 385, BD 841, 2SC2690
BD 828(A,B)	Aeg,Phi,++	Si-P	=BD 826: 60/60V	{BD827	13h	TO-202	BD 140	14h	BD 138, BD 229, BD 386, BD 842, 2SA1220
BD 829(A,B)	Aeg,Phi,++	Si-N	=BD 825: 100/100V	{BD830	13h	TO-202	BD 139	14h	BD 139, BD 230, BD 389, BD 843, 2SC2690
BD 830(A,B)	Aeg,Phi,++	Si-P	=BD 826: 100/100V	{BD829	13h	TO-202	BD 140	14h	BD 140, BD 231, BD 390, BD 844, 2SA1220
BD 833	Gen	Si-N	LF P, 45/45V, 3/5A, 15W, 50MHz	{BD834	13j	TO-202	(BD 243 C)[8]	17j	2SC1098, 2SC3252…3253
BD 834	Gen	Si-P	LF P, 45/45V, 3/5A, 15W, 40MHz	{BD833	13j	TO-202	(BD 244 C)[8]	17j	2SA636, 2SA1288…1289
BD 835	Gen	Si-N	=BD 833: 60/60V	{BD836	13j	TO-202	(BD 243 C)[8]	17j	2SC1098, 2SC3252…3253
BD 836	Gen	Si-P	=BD 834: 60/60V	{BD835	13j	TO-202	(BD 244 C)[8]	17j	2SA636, 2SA1288…1289
BD 837	Gen	Si-N	=BD 833: 100/80V	{BD838	13j	TO-202	(BD 243 C)[8]	17j	-
BD 838	Gen	Si-P	=BD 834: 100/80V	{BD837	13j	TO-202	(BD 244 C)[8]	17j	-
BD 839	Phi	Si-N	LF P, 45/45V, 1,5/3A, 10W, 125MHz	{BD840	13h	TO-202	BD 139	14h	BD 135, BD 226, BD 375, 2SC2690(A)
BD 840	Phi	Si-P	LF P, 45/45V, 1,5/3A, 10W, 50MHz	{BD839	13h	TO-202	BD 140	14h	BD 136, BD 227, BD 376, 2SA1220(A)
BD 841	Phi	Si-N	=BD 839: 60/60V	{BD842	13h	TO-202	BD 139	14h	BD 137, BD 228, BD 377, 2SC2690(A)
BD 842	Phi	Si-P	=BD 840: 60/60V	{BD841	13h	TO-202	BD 140	14h	BD 138, BD 229, BD 378, 2SA1220(A)
BD 843	Phi	Si-N	=BD 839: 100/80V	{BD844	13h	TO-202	BD 139	14h	BD 139, BD 230, BD 379, 2SC2690(A)
BD 844	Phi	Si-P	=BD 840: 100/80V	{BD843	13h	TO-202	BD 140	14h	BD 140, BD 231, BD 380, 2SA1220(A)
BD 845	Phi	Si-N	LF P, 100/100V, 1,5/3A, 10W, >150MHz	{BD846	13h	TO-202	BD 139	14h	BD 139, BD 379, BD 843, 2SC3117, 2SD669
BD 846	Phi	Si-P	LF P, 100/100V, 1,5/3A, 10W, >150MHz	{BD845	13h	TO-202	BD 140	14h	BD 140, BD 380, BD 844, 2SA1249, 2SB649
BD 847	Phi	Si-N	=BD 845: 120/120V	{BD848	13h	TO-202	2SC3117	14h	2SC2690(A), 2SC3117, 2SD669
BD 848	Phi	Si-P	=BD 846: 120/120V	{BD847	13h	TO-202	2SA1249	14h	2SA1220(A), 2SA1249, 2SB649
BD 849	Phi	Si-N	=BD 845: 140/140V	{BD850	13h	TO-202	2SC3117	14h	2SC2690A, 2SC3117, 2SD669
BD 850	Phi	Si-P	=BD 845: 140/140V	{BD849	13h	TO-202	2SA1249	14h	2SA1220A, 2SA1249, 2SB649

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BD 861	Sie	Si-N-Darl	LF P, 45/45V, 4/7A, 15W, 7MHz, hFE>750	{BD862	13h	TO-202	BD 679	14h	BD 675, BD 775, 2N6038
BD 862	Sie	Si-P-Darl	LF P, 45/45V, 4/7A, 15W, 7MHz, hFE>750	{BD861	13h	TO-202	BD 680	14h	BD 676, BD 776, 2N6035
BD 863	Sie	Si-N-Darl	=BD 861: 60/60V	{BD864	13h	TO-202	BD 679	14h	BD 677, BD 777, 2N6038
BD 864	Sie	Si-P-Darl	=BD 862: 60/60V	{BD863	13h	TO-202	BD 680	14h	BD 678, BD 778, 2N6035
BD 865	Sie	Si-N-Darl	=BD 861: 80/80V	{BD866	13h	TO-202	BD 679	14h	BD 679, BD 779, 2N6039
BD 866	Sie	Si-P-Darl	=BD 862: 80/80V	{BD865	13h	TO-202	BD 680	14h	BD 680, BD 780, 2N6036
BD 875	Sie	Si-N-Darl	60/45V, 1/2A, 9W(Tc=60°), 200MHz, hFE>2000	{BD876	14h	TO-126	(BD 679)[8]	14h	BDX 42…44
BD 876	Sie	Si-P-Darl	60/45V, 1/2A, 9W(Tc=60°), 200MHz, hFE>2000	{BD875	14h	TO-126	(BD 680)[8]	14h	BDX 45…47
BD 877	Sie	Si-N-Darl	=BD 875: 80/60V	{BD878	14h	TO-126	(BD 679)[8]	14h	BDX 43…44
BD 878	Sie	Si-P-Darl	=BD 876: 80/60V	{BD877	14h	TO-126	(BD 680)[8]	14h	BDX 46…47
BD 879	Sie	Si-N-Darl	=BD 875: 100/80V	{BD880	14h	TO-126	(BD 679)[8]	14h	BDX 44
BD 880	Sie	Si-P-Darl	=BD 876: 100/80V	{BD879	14h	TO-126	(BD 680)[8]	14h	BDX 47
BD 887	Sie	Si-P	LF P, 30/25V, 20A, 62,5W, >50MHz		17j	TO-220	(BD 250 C)[4]		(BD 250, BD 746)[4]
BD 888	Sie	Si-P	=BD 887: 45/45V		17j	TO-220	(BD 250 C)[4]		(BD 250, BD 746)[4]
BD 895(A)	Mot,Tix,++	Si-N-Darl+Di	LF P, 45/45V, 8A, 70W, >1MHz, hFE>750	{BD896	17j	TO-220	BD 901	17j	BD 643, BDW 73, BDX 33, BDX 53, ++
BD 896(A)	Mot,Tix,++	Si-P-Darl+Di	LF P, 45/45V, 8A, 70W, >1MHz, hFE>750	{BD895	17j	TO-220	BD 902	17j	BD 644, BDW 74, BDX 34, BDX 54, ++
BD 897(A)	Mot,Tix,++	Si-N-Darl+Di	=BD 895: 60/60V	{BD898	17j	TO-220	BD 901	17j	BD 645, BDW 73A, BDX 33A, BDX 53A, ++
BD 898(A)	Mot,Tix,++	Si-P-Darl+Di	=BD 896: 60/60V	{BD897	17j	TO-220	BD 902	17j	BD 646, BDW 74A, BDX 34A, BDX 54A, ++
BD 899(A)	Mot,Tix,++	Si-N-Darl+Di	=BD 895: 80/80V	{BD900	17j	TO-220	BD 901	17j	BD 647, BDW 73B, BDX 33B, BDX 53B, ++
BD 900(A)	Mot,Tix,++	Si-P-Darl+Di	=BD 896: 80/80V	{BD899	17j	TO-220	BD 902	17j	BD 648, BDW 74B, BDX 34B, BDX 54B, ++
BD 901	Mot,Tix,++	Si-N-Darl+Di	=BD 895: 100/100V	{BD902	17j	TO-220	BD 901	17j	BD 649, BDW 73C, BDX 33C, BDX 53C, ++
BD 902	Mot,Tix,++	Si-P-Darl+Di	=BD 896: 100/100V	{BD901	17j	TO-220	BD 902	17j	BD 650, BDW 74C, BDX 34C, BDX 54C, ++
BD 905	Tho	Si-N	LF P, 45/45V, 15A, 90W, >3MHz	{BD906	17j	TO-220			BD 743, BDT 81
BD 906	Tho	Si-P	LF P, 45/45V, 15A, 90W, >3MHz	{BD905	17j	TO-220			BD 744, BDT 82
BD 907	Tho	Si-N	=BD 905: 60/60V	{BD908	17j	TO-220			BD 743A, BDT 81
BD 908	Tho	Si-P	=BD 906: 60/60V	{BD907	17j	TO-220			BD 744A, BDT 82
BD 909	Tho	Si-N	=BD 905: 80/80V	{BD910	17j	TO-220			BD 743B, BDT 83
BD 910	Tho	Si-P	=BD 906: 80/80V	{BD909	17j	TO-220			BD 744B, BDT 84
BD 911	Tho	Si-N	=BD 905: 100/100V	{BD912	17j	TO-220			BD 743C, BDT 85
BD 912	Tho	Si-P	=BD 906: 100/100V	{BD911	17j	TO-220			BD 744C, BDT 86
BD 933	Phi	Si-N	LF P, 45/45V, 3/7A, 30W, >3MHz, 400/1500ns	{BD934	17j	TO-220	BD 243 C	17j	BD 241, BD 533, BD 539A, BD 947, ++
BD 933 F		Si-N	=BD 933: Iso, >14W		17c	SOT-186	2SD1411	17c	BD 947F, BDT 31F, 2SD1985, 2SD2012, ++
BD 934	Phi	Si-P	LF P, 45/45V, 3/7A, 30W, >3MHz, 300/700ns	{BD933	17j	TO-220	BD 244 C	17j	BD 242, BD 534, BD 540A, BD 948, ++
BD 934 F		Si-P	=BD 934: Iso, >14W		17c	SOT-186	2SB1018	17c	BD 948F, BDT 32F, 2SB1015, 2SB1094, ++
BD 935	Phi	Si-N	=BD 933: 60/60V	{BD936	17j	TO-220	BD 243 C	17j	BD 241A, BD 535, BD 539A, BD 949, ++
BD 935 F		Si-N	=BD 935: Iso, >14W		17c	SOT-186	2SD1411	17c	BD 949F, BDT 31F, 2SD1985, 2SD2012, ++
BD 936		Si-P	=BD 934: 60/60V	{BD935	17j	TO-220	BD 244 C	17j	BD 242A, BD 536, BD 540A, BD 950, ++
BD 936 F		Si-P	=BD 936: Iso, >14W		17c	SOT-186	2SB1018	17c	BD 950F, BDT 32F, 2SB1015, 2SB1094, ++
BD 937	Phi	Si-N	=BD 933: 100/80V	{BD938	17j	TO-220	BD 243 C	17j	BD 241C, BD 539C, BD 953, 2SD712, ++
BD 937 F		Si-N	=BD 937: Iso, >14W		17c	SOT-186	2SD1411	17c	BD 953F, BDT 31AF, 2SD1407, 2SD1586, ++
BD 938	Phi	Si-P	=BD 934: 100/80V	{BD937	17j	TO-220	BD 244 C	17j	BD 242C, BD 540C, BD 954, 2SB682, ++
BD 938 F		Si-P	=BD 938: Iso, >14W		17c	SOT-186	2SB1018	17c	BD 954F, BDT 32AF, 2SB1095, 2SB1294, ++
BD 939	Phi	Si-N	=BD 933: 120/100V	{BD940	17j	TO-220	BD 243 C	17j	BD 241C, BD 539D, BD 955, 2SD959…961,++
BD 939 F		Si-N	=BD 939: Iso, >14W		17c	SOT-186	(BD 243 C)[3]	17j	BD 955F, BDT 31BF, 2SC3566, 2SC4334, ++
BD 940	Phi	Si-P	=BD 934: 120/100V	{BD939	17j	TO-220	BD 244 C	17j	BD 242C, BD 540D, BD 956, 2SB867…869,++
BD 940 F		Si-P	=BD 940: Iso, >14W		17c	SOT-186	(BD 244 C)[3]	17j	BD 956F, BDT 32BF, 2SA1650
BD 941	Phi	Si-N	=BD 933: 140/120V	{BD942	17j	TO-220			BD 241D, BD 243D, 2SC2516
BD 941 F		Si-N	=BD 941: Iso, >14W		17c	SOT-186			BDT 31CF, 2SC3566, 2SC4334
BD 942	Phi	Si-P	=BD 934: 140/120V	{BD941	17j	TO-220			BD 242D, BD 244D
BD 942 F		Si-P	=BD 942: Iso, >14W		17c	SOT-186			BDT 32CF, 2SA1650
BD 943	Phi	Si-N	LF P, 22/22V, 5/8A, 40W, >3MHz	{BD944	17j	TO-220	BD 243 C	17j	BD 243, BD 539, BD 795, BD 943, ++
BD 943 F		Si-N	=BD 943: Iso, >15W		17c	SOT-186	2SD1411	17c	BD 949F, BDT 41F, BDT 91F, 2SD1667, ++
BD 944	Phi	Si-P	LF P, 22/22V, 5/8A, 40W, >3MHz	{BD943	17j	TO-220	BD 244 C	17j	BD 244, BD 540, BD 796, BD 944, ++
BD 944 F		Si-P	=BD 944: Iso, >15W		17c	SOT-186	2SB1018	17c	BD 950F, BDT 42F, BDT 92F, 2SB1134, ++
BD 945	Phi	Si-N	=BD 943: 32/32V	{BD946	17j	TO-220	BD 243 C	17j	BD 243, BD 539, BD 795, BD 945, ++
BD 945 F		Si-N	=BD 945: Iso, >15W		17c	SOT-186	2SD1411	17c	BD 949F, BDT 41F, BDT 91F, 2SD1667, ++
BD 946	Phi	Si-P	=BD 944: 32/32V	{BD945	17j	TO-220	BD 244 C	17j	BD 244, BD 540, BD 796, BD 946, ++
BD 946 F		Si-P	=BD 946: Iso, >15W		17c	SOT-186	2SB1018	17c	BD 950F, BDT 42F, BDT 92F, 2SB1134, ++
BD 947	Phi	Si-N	=BD 943: 45/45V	{BD948	17j	TO-220	BD 243 C	17j	BD 243A, BD 539A, BD 975, BD 947, ++
BD 947 F		Si-N	=BD 947: Iso, >15W		17c	SOT-186	2SD1411	17c	BD 949F, BDT 41F, BDT 91F, 2SD1667, ++
BD 948	Phi	Si-P	=BD 944: 45/45V	{BD947	17j	TO-220	BD 244 C	17j	BD 244A, BD 540A, BD 796, BD 948, ++
BD 948 F		Si-P	=BD 948: Iso, >15W		17c	SOT-186	2SB1018	17c	BD 950F, BDT 42F, BDT 92F, 2SB1134, ++
BD 949	Phi	Si-N	LF P, 60/60V, 5/8A, 40W, >3MHz, 300/1500ns	{BD950	17j	TO-220	BD 243 C	17j	BD 243A, BD 539A, BD 543A, BD 797, ++
BD 949 F		Si-N	=BD 949: Iso, >15W		17c	SOT-186	2SD1411	17c	BDT 41F, BDT 91F, BDX 77F, 2SD1667, ++
BD 950	Phi	Si-P	LF P, 60/60V, 5/8A, 40W, >3MHz, 100/400ns	{BD949	17j	TO-220	BD 244 C	17j	BD 244A, BD 540A, BD 544A, BD 798, ++
BD 950 F		Si-P	=BD 950: Iso, >15W		17c	SOT-186	2SB1018	17c	BDT 42F, BDT 92F, BDX 78F, 2SB1134, ++
BD 951	Phi	Si-N	=BD 949: 80/80V	{BD952	17j	TO-220	BD 243 C	17j	BD 243B, BD 539B, BD 543B, BD 799, ++
BD 951 F		Si-N	=BD 951: Iso, >15W		17c	SOT-186	2SD1411	17c	BDT 41F, BDT 93F, BDX 77F, 2SD1940, ++
BD 952	Phi	Si-P	=BD 950: 80/80V	{BD951	17j	TO-220	BD 244 C	17j	BD 244B, BD 540B, BD 544B, BD 800, ++
BD 952 F		Si-P	=BD 952: Iso, >15W		17c	SOT-186	2SB1018	17c	BDT 42F, BDT 94F, BDX 78F, 2SB1294, ++
BD 953	Phi	Si-N	=BD 949: 100/100V	{BD954	17j	TO-220	BD 243 C	17j	BD 243C, BD 539C, BD 543C, BD 801, ++
BD 953 F		Si-N	=BD 953: Iso, >15W		17c	SOT-186	2SD1411	17c	BDT 41AF, BDT 95F, BDX 77F, 2SD1940, ++
BD 954	Phi	Si-P	=BD 950: 100/100V	{BD953	17j	TO-220	BD 244 C	17j	BD 244C, BD 540C, BD 544C, BD 802, ++
BD 954 F		Si-P	=BD 954: Iso, >15W		17c	SOT-186	2SB1018	17c	BDT 42AF, BDT 96F, BDX 78F, 2SB1294, ++
BD 955	Phi	Si-N	=BD 949: 120/120V	{BD956	17j	TO-220	(BD 243 C)	17j	BD 543D, 2SD866
BD 955 F		Si-N	=BD 955: Iso, >15W		17c	SOT-186	(BD 243 C)[3]	17j	BDT 41BF, 2SC4334…35
BD 956	Phi	Si-P	=BD 950: 120/120V	{BD955	17j	TO-220			BD 544D, 2SB870
BD 956 F		Si-P	=BD 956: Iso, >15W		17c	SOT-186	(BD 244 C)[3]	17j	BDT 42BF, 2SA1650…51
BD 975	Sie	Si-N-Darl	LF P, 60/45V, 1/2A, 3,6W(Tc=60°), 200MHz	{BD976	13h	TO-202	(BD 679)[8]	14h	BDX 42…44
BD 976	Sie	Si-P-Darl	LF P, 60/45V, 1/2A, 3,6W(Tc=60°), 200MHz	{BD975	13h	TO-202	(BD 680)[8]	14h	BDX 45…47
BD 977	Sie	Si-N-Darl	=BD 975: 80/60V	{BD978	13h	TO-202	(BD 679)[8]	14h	BDX 43…44
BD 978	Sie	Si-P-Darl	=BD 976: 80/60V	{BD977	13h	TO-202	(BD 680)[8]	14h	BDX 46…47
BD 979	Sie	Si-N-Darl	=BD 975: 100/80V	{BD980	13h	TO-202	(BD 679)[8]	14h	BDX 44
BD 980	Sie	Si-P-Darl	=BD 976: 100/80V	{BD979	13h	TO-202	(BD 680)[8]	14h	BDX 47
BD 1540	Ssc	Si-N-Darl	S P, 400/400V, 15A, 100W, 7MHz, hFE>100		23a	TO-3			BU 930…932, 2SD572…573, 2SD711, ++
BD 1550	Ssc	Si-N-Darl	=BD 1540: 500/500V		23a	TO-3			BU 932, 2SD572…573, 2SD683, 2SD711, ++
BD 1560	Ssc	Si-N-Darl	=BD 1540: 600/600V		23a	TO-3			2SD573, 2SD606, 2SD683, 2SD711A, ++
BD 2530	Ssc	Si-N-Darl	S P, 300/300V, 25A, 100W, 7MHz, hFE>100		23a	TO-3			BUT 13
BD 2540	Ssc	Si-N-Darl	=BD 2530: 400/400V		23a	TO-3			BUT 13
BD 2550	Ssc	Si-N-Darl	=BD 2530: 500/500V		23a	TO-3			BUT 13

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BDB....BDS									
BDB 01A	Mot	Si-N	LF Drv,Out, 45/45V, 0,5A, 1W, >50MHz	{BDB02	7e(9mm)	TO-92L	2SD1812	7c(9mm)	2SC2235, 2SD667(A), 2SD863, 2SD1292,++
BDB 01B		Si-N	=BDB 01A: 60/60V		7e(9mm)	TO-92L	2SD1812	7c(9mm)	2SC2235, 2SD667(A), 2SD863, 2SD1292,++
BDB 01C		Si-N	=BDB 01A: 80/80V		7e(9mm)	TO-92L	2SD1812	7c(9mm)	2SC2235, 2SD667(A), 2SD1292, 2SD1812,++
BDB 01D		Si-N	=BDB 01A: 100/100V		7e(9mm)	TO-92L	2SD1812	7c(9mm)	2SC2235, 2SD667(A), 2SD1292, 2SD1812,++
BDB 02A	Mot	Si-P	LF Drv,Out, 45/45V, 0,5A, 1W, >50MHz	{BDB01	7e(9mm)	TO-92L	2SB1212	7c(9mm)	2SA965, 2SB647(A), 2SB764, 2SB1041,++
BDB 02B		Si-P	=BDB 02A: 60/60V		7e(9mm)	TO-92L	2SB1212	7c(9mm)	2SA965, 2SB647(A), 2SB764, 2SB1041,++
BDB 02C		Si-P	=BDB 02A: 80/80V		7e(9mm)	TO-92L	2SB1212	7c(9mm)	2SA965, 2SB647(A), 2SB1041, 2SB1212,++
BDB 02D		Si-P	=BDB 02A: 100/100V		7e(9mm)	TO-92L	2SB1212	7c(9mm)	2SA965, 2SA1275, 2SB647(A), 2SB1212,++
BDB 03	Mot	Si-N	LF Drv,Out, 60/45V, 1A, 1W, >150MHz	{BDB04	7e(9mm)	TO-92L	2SD1812	7c(9mm)	2SC2235, 2SD667(A), 2SD863, 2SD1292,++
BDB 04	Mot	Si-P	LF Drv,Out, 60/45V, 1A, 1W, >150MHz	{BDB03	7e(9mm)	TO-92L	2SB1212	7c(9mm)	2SA965, 2SB647(A), 2SB764, 2SB1041,++
BDB 05	Mot	Si-N	LF Drv,Out, 120/80V, 1A, 1W, >100MHz	{BDB06	7e(9mm)	TO-92L	2SD1812	7c(9mm)	2SC3228, 2SD667(A), 2SD1292, 2SD1812,++
BDB 06	Mot	Si-P	LF Drv,Out, 80/80V, 1A, 1W, >150MHz	{BDB05	7e(9mm)	TO-92L	2SB1212	7c(9mm)	2SA965, 2SA1275, 2SB647(A), 2SB1212,++
BDC 01(A....D)	Mot	Si-N	=BDB 01(A...D):	{BDC02	7c(9mm)	TO-92L	›BDB 01...		›BDB 01(A...D)
BDC 02(A....D)	Mot	Si-P	=BDB 02(A...D):	{BDC01	7c(9mm)	TO-92L	›BDB 02...		›BDB 02(A...D)
BDC 03	Mot	Si-N	LF Drv,Out, 25/20V, 1A, 1W, >50MHz	{BDC04	7c(9mm)	TO-92L	2SD1207	7c(9mm)	2SC2236, 2SD863, 2SD1146, 2SD1331,++
BDC 04	Mot	Si-P	LF Drv,Out, 25/20V, 1A, 1W, >50MHz	{BDC03	7c(9mm)	TO-92L	2SB892	7c(9mm)	2SA966, 2SB764, 2SB978, 2SB892,++
BDC 05	Mot	Si-N	Vid, 300/300V, 0,5A, 1W, >60MHz	{BDC06	7c(9mm)	TO-92L	(MPS-U10)[5]	13m	(BF 382, BF 461, BF 758, MPS-U10)[5]
BDC 06	Mot	Si-P	Vid, 300/300V, 0,5A, 1W, >60MHz	{BDC05	7c(9mm)	TO-92L	(MPS-U60)[5]	13m	(BF 464, BF 761, MPS-U60)[5]
BDC 07	Mot	Si-N	=BDC 05: 250/250V	{BDC08	7c(9mm)	TO-92L	(MPS-U10)[5]	13m	(BF 381, BF 460, BF 757, MPS-U10)[5]
BDC 08	Mot	Si-P	=BDC 06: 250/250V	{BDC07	7c(9mm)	TO-92L	(MPS-U60)[5]	13m	(BF 463, BF 760, MPS-U60)[5]
BDD		Z-Di	=SM 15T 6V8C(SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BDE		Z-Di	=SM 15T6V8CA(SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BDF		Z-Di	=SM 15T 7V5C(SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BDG		Z-Di	=SM 15T7V5CA(SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BDM		Si-P	=2SA1733K-M (SMD-Marking)		35	SOT-23			›2SA1733K
BDM		Si-P	=2SA1808-M (SMD-Marking)		35(2mm)	SOT-323			›2SA1808
BDN		Si-P	=2SA1733K-N (SMD-Marking)		35	SOT-23			›2SA1733K
BDN		Si-P	=2SA1808-N (SMD-Marking)		35(2mm)	SOT-323			›2SA1808
BDN		Z-Di	=SM 15T 10C (SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BDP		Si-P	=2SA1733K-P (SMD-Marking)		35	SOT-23			›2SA1733K
BDP		Si-P	=2SA1808-P (SMD-Marking)		35(2mm)	SOT-323			›2SA1808
BDP		Si-P	=2SB1189-P (SMD-Marking)		39	SOT-89			›2SB1189
BDP		Z-Di	=SM 15T 10CA(SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BDP 31	Phi	Si-N	Uni, 70/45V, 3/6A, 1,5W, 60MHz	{BDP32	≈39°j	SOT-223			-
BDP 32	Phi	Si-P	Uni, 45/45V, 3/6A, 1,5W, 60MHz	{BDP31	≈39°j	SOT-223			-
BDP 4148	Say	Si-Di	Di Array, 8x 1N4148		16-DIP				-
BDQ		Si-P	=2SB1189-Q (SMD-Marking)		39	SOT-89			›2SB1189
BDR		Si-P	=2SB1189-R (SMD-Marking)		39	SOT-89			›2SB1189
BDS		Z-Di	=SM 15T 12C (SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BDS 60 (A...C)	Phi	Si-P-Darl+Di	=BDT 60...: 3/6A, 8W	{BDS61	≈39°j	SOT-223			-
BDS 61 (A...C)	Phi	Si-N-Darl+Di	=BDT 61...: 3/6A, 8W	{BDS60	≈39°j	SOT-223			-
BDS 77	Phi	Si-N	=BDX 77: 3/7A, 8W	{BDS78	≈39°j	SOT-223			-
BDS 78	Phi	Si-P	=BDX 78: 3/7A, 8W	{BDS77	≈39°j	SOT-223			-
BDS 201...BDS 204	Phi	Si-N/P	=BD 201...204: 3/7A, 8W		≈39°j	SOT-223			-
BDS 643...BDS 652	Phi	Si-N/P-Darl	=BD 643...652: 3/7A, 8W		≈39°j	SOT-223			-
BDS 933...BDS 942	Phi	Si-N/P	=BD 933...942: 3/6A, 8W		≈39°j	SOT-223			-
BDS 943...BDS 948	Phi	Si-N/P	=BD 943...948: 3/7A, 8W		≈39°j	SOT-223			-
BDS 949...BDS 956	Phi	Si-N/P	=BD 949...956: 3/7A, 8W		≈39°j	SOT-223			-
BDT									
BDT		Z-Di	=SM 15T 12CA(SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BDT 20	Phi	Si-P-Darl+Di	LF P, 130/130V, 8/12A, 62,5W, hFE>750	{BDT21	17j	TO-220			BDX 54E
BDT 21	Phi	Si-N-Darl	LF P, 130/130V, 8/12A, 62,5W, hFE>750	{BDT20	17j	TO-220			BDX 53, 2SD1386, 2SD1025, 2SD1500
BDT 29	Phi	Si-N	LF P, 80/40V, 1/3A, 30W, >3MHz	{BDT30	17j	TO-220	2SD1138	17j	BD 239B, BD 241B, BD 537, BD 937, ++
BDT 29 A		Si-N	=BDT 29: 100/60V		17j	TO-220	2SD1138	17j	BD 239C, BD 241C, BD 937, 2SD1138, ++
BDT 29 AF		Si-N	=BDT 29: Iso, 100/60V, >15W		17c	SOT-186	2SC4159	17c	BD 937F, BDT 31AF, 2SC3298, 2SD1586, ++
BDT 29 B		Si-N	=BDT 29: 120/80V		17j	TO-220	2SD1138	17j	BD 239C, BD 241C, BD 939, 2SD1138, ++
BDT 29 BF		Si-N	=BDT 29: Iso, 120/80V, >15W		17c	SOT-186	2SC4159	17c	BD 939F, BDT 31BF, 2SC3298, 2SD1587, ++
BDT 29 C		Si-N	=BDT 29: 140/100V		17j	TO-220	2SD1138	17j	BD 239D, BD 241D, 2SD1138, 2SD1459, ++
BDT 29 CF		Si-N	=BDT 29: Iso, 140/100V, >15W		17c	SOT-186	2SC4159	17c	BD 941F, BDT 31CF, 2SC3298, 2SD1587, ++
BDT 29 DF		Si-N	=BDT 29: Iso, 160/120V, >15W		17c	SOT-186	2SC4159	17c	BDT 31DF, 2SC3298(A...B), 2SD1587, ++
BDT 29 F		Si-N	=BDT 29: Iso, >15W		17c	SOT-186	2SC4159	17c	BD 937F, BDT 31F, 2SC3851, 2SD1408, ++
BDT 30	Phi	Si-P	LF P, 80/40V, 1/3A, 30W, >3MHz	{BDT29	17j	TO-220	2SB861	17j	BD 240B, BD 242B, BD 538, BD 938, ++
BDT 30 A		Si-P	=BDT 30: 100/60V		17j	TO-220	2SB861	17j	BD 240C, BD 242C, BD 938, 2SB861, ++
BDT 30 AF		Si-P	=BDT 30: Iso, 100/60V, >15W		17c	SOT-186	2SA1606	17c	BD 938F, BDT 32AF, 2SA1306, 2SB1095, ++
BDT 30 B		Si-P	=BDT 30: 120/80V		17j	TO-220	2SB861	17j	BD 240C, BD 242C, BD 940, 2SB861, ++
BDT 30 BF		Si-P	=BDT 30: Iso, 120/80V, >15W		17c	SOT-186	2SA1606	17c	BD 940F, BDT 32BF, 2SA1306, 2SB1096, ++
BDT 30 C		Si-P	=BDT 30: 140/100V		17j	TO-220	2SB861	17j	BD 240D, BD 242D, 2SB861, 2SB1037, ++
BDT 30 CF		Si-P	=BDT 30: Iso, 140/100V, >15W		17c	SOT-186	2SA1606	17c	BD 942F, BDT 32CF, 2SA1306, 2SB1096, ++
BDT 30 DF		Si-P	=BDT 30: Iso, 160/120V, >15W		17c	SOT-186	2SA1606	17c	BDT 32DF, 2SA1306(A...B), 2SB1096, ++
BDT 30 F		Si-P	=BDT 30: Iso, >15W		17c	SOT-186	2SA1606	17c	BD 938F, BDT 32F, 2SA1635, 2SB1017, ++
BDT 31	Phi	Si-N	LF P, 80/40V, 3/5A, 40W, >3MHz	{BDT32	17j	TO-220	BD 243 C	17j	BD 241B, BD 537, BD 539B, BD 937, ++
BDT 31 A		Si-N	=BDT 31: 100/60V		17j	TO-220	BD 243 C	17j	BD 241C, BD 243C, BD 539C, BD 937, ++
BDT 31 AF		Si-N	=BDT 31: Iso, 100/60V, >15W		17c	SOT-186	2SD1411	17c	BD 937F, BD 953F, BDT 41AF, 2SD1586, ++
BDT 31 B		Si-N	=BDT 31: 120/80V		17j	TO-220	BD 243 C	17j	BD 241C, BD 243C, BD 539D, BD 939, ++
BDT 31 BF		Si-N	=BDT 31: Iso, 120/80V, >15W		17c	SOT-186	(BD 243 C)[3]	17j	BD 939F, BD 955F, BDT 41BF, 2SC3566, ++
BDT 31 C		Si-N	=BDT 31: 140/100V		17j	TO-220	2SC2334	17j	BD 241D, BD 243D, BD 941
BDT 31 CF		Si-N	=BDT 31: Iso, 140/100V, >15W		17c	SOT-186	(2SC2334)[3]	17j	BD 941F, BDT 41CF, 2SC3566, 2SC4334
BDT 31 DF		Si-N	=BDT 31: Iso, 160/120V, >15W		17c	SOT-186			2SC4153
BDT 31 F		Si-N	=BDT 31: Iso, >15W		17c	SOT-186	2SD1411	17c	BD 937F, BD 951F, BDT 41F, 2SD1586, ++
BDT 32	Phi	Si-P	LF P, 80/40V, 3/5A, 40W, >3MHz	{BDT31	17j	TO-220	BD 244 C	17j	BD 242B, BD 538, BD 540B, BD 938, ++
BDT 32 A		Si-P	=BDT 32: 60/60V		17j	TO-220	BD 244 C	17j	BD 242B, BD 244B, BD 540B, BD 938, ++
BDT 32 AF		Si-P	=BDT 32: Iso, 60/60V, >15W		17c	SOT-186	2SB1018	17c	BD 938F, BD 954F, BDT 42AF, 2SB1095, ++
BDT 32 B		Si-P	=BDT 32: 80/80V		17j	TO-220	BD 244 C	17j	BD 242C, BD 244C, BD 540D, BD 940, ++
BDT 32 BF		Si-P	=BDT 32: Iso, 80/80V, >15W		17c	SOT-186	2SB1018	17c	BD 940F, BD 956F, BDT 42BF, 2SA1650, ++
BDT 32 C		Si-P	=BDT 32: 100/100V		17j	TO-220	BD 244 C	17j	BD 242C, BD 244C, BD 540D, BD 940
BDT 32 CF		Si-P	=BDT 32: Iso, 100/100V, >15W		17c	SOT-186	2SB1018	17c	BD 942F, BDT 42CF, 2SA1650
BDT 32 DF		Si-P	=BDT 32: Iso, 160/120V, >15W		17c	SOT-186			-
BDT 32 F		Si-P	=BDT 32: Iso, >15W		17c	SOT-186	2SB1018	17c	BD 938F, BD 952F, BDT 42F, 2SB1095, ++
BDT 41	Phi	Si-N	LF P, 80/40V, 6/10A, 65W, >3MHz	{BDT42	17j	TO-220	BD 243 C	17j	BD 243B, BD 543B, BD 799, BD 809, ++
BDT 41 A		Si-N	=BDT 41: 100/60V		17j	TO-220	BD 243 C	17j	BD 243C, BD 543C, BD 801, 2SD866, ++

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BDT 41 AF		Si-N	=BDT 41: Iso, 100/60V, >20W		17c	SOT-186	2SD1411	17c	BDT 95F, BDX 77F, 2SD1411, 2SD1588, ++
BDT 41 B		Si-N	=BDT 41: 120/80V		17j	TO-220	BD 243 C	17j	BD 243C, BD 543D, 2SD866
BDT 41 BF		Si-N	=BDT 41: Iso, 120/80V, >20W		17c	SOT-186	(BD 243 C)[3]	17j	2SC4335, 2SD1271
BDT 41 C		Si-N	=BDT 41: 140/100V		17j	TO-220	2SC2334	17j	BD 243D, 2SC4329
BDT 41 CF		Si-N	=BDT 41: Iso, 140/100V, >20W		17c	SOT-186			2SC4153, 2SC4335
BDT 41 F		Si-N	=BDT 41: Iso, >20W		17c	SOT-186	2SD1411	17c	BDT 93F, BDX 77F, 2SD1411, 2SD1588, ++
BDT 42	Phi	Si-P	LF P, 80/40V, 6/10A, 65W, >3MHz	{BDT41	17j	TO-220	BD 244 C	17j	BD 244B, BD 544B, BD 800, BD 810, ++
BDT 42 A		Si-P	=BDT 42: 100/60V		17j	TO-220	BD 244 C	17j	BD 244C, BD 544C, BD 802, 2SB870, ++
BDT 42 AF		Si-P	=BDT 42: Iso, 100/60V, >20W		17c	SOT-186	2SB1018	17c	BDT 96F, BDX 78F, 2SB1018, 2SB1290, ++
BDT 42 B		Si-P	=BDT 42: 120/80V		17j	TO-220	BD 244 C	17j	BD 244C, BD 544D, 2SB870
BDT 42 BF		Si-P	=BDT 42: Iso, 120/80V, >20W		17c	SOT-186	(BD 244 C)[3]	17j	2SA1651
BDT 42 C		Si-P	=BDT 42: 140/100V		17j	TO-220			BD 244D
BDT 42 CF		Si-P	=BDT 42: Iso, 140/100V, >20W		17c	SOT-186			2SA1651
BDT 42 F		Si-P	=BDT 42: Iso, >20W		17c	SOT-186	2SB1018	17c	BDT 94F, BDX 78F, 2SB1018, 2SB1290, ++
BDT 51	Phi	Si-N	LF,S P, 60/60V, 15/25A, 90W	{BDT52	17j	TO-220			BD 743A, BD 907, BDT 81
BDT 52	Phi	Si-P	LF,S P, 60/60V, 15/25A, 90W	{BDT51	17j	TO-220			BD 744A, BD 908, BDT 82
BDT 53	Phi	Si-N	=BDT 51: 80/80V	{BDT54	17j	TO-220			BD 743B, BD 909, BDT 83
BDT 54	Phi	Si-P	=BDT 52: 80/80V	{BDT53	17j	TO-220			BD 744B, BD 910, BDT 84
BDT 55	Phi	Si-N	=BDT 51: 100/100V	{BDT56	17j	TO-220			BD 743C, BD 911, BDT 85
BDT 56	Phi	Si-P	=BDT 52: 100/100V	{BDT55	17j	TO-220			BD 744C, BD 912, BDT 86
BDT 57	Phi	Si-N	=BDT 51: 120/120V	{BDT58	17j	TO-220			BD 743D, BDT 87
BDT 58	Phi	Si-P	=BDT 52: 120/120V	{BDT57	17j	TO-220			BD 744D, BDT 88
BDT 60	Phi	Si-P-Darl+Di	LF P, 60/60V, 4/6A, 50W, >10MHz, hFE>750	{BDT61	17j	TO-220	BD 902	17j	BD 716, BDW 24A, BDW 54A, BDW 64A
BDT 60 A		Si-P-Darl+Di	=BDT 60: 80/80V		17j	TO-220	BD 902	17j	BD 718, BDW 24B, BDW 54B, BDW 64B
BDT 60 AF		Si-P-Darl+Di	=BDT 60: Iso, 80/80V, >17W		17c	SOT-186	2SB1020	17c	BD 648F, 2SB1342, 2SB1282, 2SB1024, ++
BDT 60 B		Si-P-Darl+Di	=BDT 60: 100/100V		17j	TO-220	BD 902	17j	BDW 24C, BDW 54C, BDW 64C
BDT 60 BF		Si-P-Darl+Di	=BDT 60: Iso, 100/100V, >17W		17c	SOT-186	2SB1020	17c	BD 650F, 2SB1024, 2SB1282, 2SB1098, ++
BDT 60 C		Si-P-Darl+Di	=BDT 60: 120/120V		17j	TO-220			BDW 54D, BDW 64D
BDT 60 CF		Si-P-Darl+Di	=BDT 60: Iso, 120/120V, 17W		17c	SOT-186			BD 652F, 2SB1340, 2SB1344
BDT 60 F		Si-P-Darl+Di	=BDT 60: Iso, >17W		17c	SOT-186	2SB1020	17c	BD 646F, 2SB1257, 2SB1223, 2SB1342, ++
BDT 60 L		Si-P-Darl+Di	=BDT 60: 45/45V		17j	TO-220	BD 902	17j	BD 714, BDW 24, BDW 54, BDW 64
BDT 61	Phi	Si-N-Darl+Di	LF P, 60/60V, 4/6A, 50W, >10MHz, hFE>750	{BDT60	17j	TO-220	BD 901	17j	BD 715, BDW 23A, BDW 53A, BDW 63A
BDT 61 A		Si-N-Darl+Di	=BDT 61: 80/80V		17j	TO-220	BD 901	17j	BD 717, BDW 23B, BDW 53B, BDW 63B
BDT 61 AF		Si-N-Darl+Di	=BDT 61: Iso, 80/80V, >17W		17c	SOT-186	2SD1415	17c	BD 645F, 2SD1933, 2SD2014, 2SD1788, ++
BDT 61 B		Si-N-Darl+Di	=BDT 61: 100/100V		17j	TO-220	BD 901	17j	BDW 23C, BDW 53C, BDW 63C
BDT 61 BF		Si-N-Darl+Di	=BDT 61: Iso, 100/100V, >17W		17c	SOT-186	2SD1415	17c	BD 647F, 2SD1414, 2SD1788, 2SD1589, ++
BDT 61 C		Si-N-Darl+Di	=BDT 61: 120/120V		17j	TO-220			BDW 53D, BDW 63D, 2SD1147
BDT 61 CF		Si-N-Darl+Di	=BDT 61: Iso, 120/120V, >17W		17c	SOT-186			BD 649F, 2SD1785, 2SD1590
BDT 61 F		Si-N-Darl+Di	=BDT 61: Iso, >17W		17c	SOT-186	2SD1415	17c	BD 643F, 2SD1796, 2SD1825, 2SD1933, ++
BDT 61 L		Si-N-Darl+Di	=BDT 61: 45/45V		17j	TO-220	BD 901	17j	BD 713, BDW 23, BDW 53, BDW 63
BDT 62	Phi	Si-P-Darl+Di	LF P, 60/60V, 10/15A, 90W, >10MHz, hFE>1000	{BDT63	17j	TO-220	BDW 94 C	17j	BDT 64, BDW 94A, BDX 34A
BDT 62 A		Si-P-Darl+Di	=BDT 62: 80/80V		17j	TO-220	BDW 94 C	17j	BDT 64A, BDW 94B, BDX 34B
BDT 62 AF		Si-P-Darl+Di	=BDT 62: Iso, 80/80V, >17W		17c	SOT-186	(BDW 94 C)[3]	17j	BDT 64AF, 2SB1100, 2SB1284, 2SB1259
BDT 62 B		Si-P-Darl+Di	=BDT 62: 100/100V		17j	TO-220	BDW 94 C	17j	BDT 64B, BDW 94C, BDX 34C
BDT 62 BF		Si-P-Darl+Di	=BDT 62: Iso, 100/100V, >17W		17c	SOT-186	(BDW 94 C)[3]	17j	BDT 64BF, 2SB1100, 2SB1284, 2SB1259
BDT 62 C		Si-P-Darl+Di	=BDT 62: 120/120V		17j	TO-220			BDT 64C, BDX 34D
BDT 62 CF		Si-P-Darl+Di	=BDT 62: Iso, 120/120V, >17W		17c	SOT-186			BDT 64CF
BDT 62 F		Si-P-Darl+Di	=BDT 62: Iso, >17W		17c	SOT-186	(BDW 94 C)[3]	17j	BDT 64F, 2SB1225, 2SB1100, 2SB1284, ++
BDT 63	Phi	Si-N-Darl+Di	LF P, 60/60V, 10/15A, 90W, >10MHz, hFE>1000	{BDT62	17j	TO-220	BDW 93 C	17j	BDT 65, BDW 93A, BDX 33A
BDT 63 A		Si-N-Darl+Di	=BDT 63: 80/80V		17j	TO-220	BDW 93 C	17j	BDT 65A, BDW 93B, BDX 33B
BDT 63 AF		Si-N-Darl+Di	=BDT 63: Iso, 80/80V, >17W		17c	SOT-186	(BDW 93 C)[3]	17j	BDT 65AF, 2SD1793, 2SD1591
BDT 63 B		Si-N-Darl+Di	=BDT 63: 100/100V		17j	TO-220	BDW 93 C	17j	BDT 65B, BDW 93C, BDX 33C
BDT 63 BF		Si-N-Darl+Di	=BDT 63: Iso, 100/100V, >17W		17c	SOT-186	(BDW 93 C)[3]	17j	BDT 65BF, 2SD1793, 2SD1591
BDT 63 C		Si-N-Darl+Di	=BDT 63: 120/120V		17j	TO-220			BDT 65C, BDX 33D
BDT 63 CF		Si-N-Darl+Di	=BDT 63: Iso, 120/120V, >17W		17c	SOT-186			BDT 65CF, 2SD1591
BDT 63 F		Si-N-Darl+Di	=BDT 63: Iso, >17W		17c	SOT-186	(BDW 93 C)[3]	17j	BDT 65F, 2SD1827, 2SD1793, 2SD1591
BDT 64	Phi	Si-P-Darl+Di	LF P, 60/60V, 12/20A, 125W, >10MHz, hFE>1000	{BDT64	17j	TO-220	BDW 94 C	17j	BDW 45, BDW 94A
BDT 64 A		Si-P-Darl+Di	=BDT 64: 80/80V		17j	TO-220	BDW 94 C	17j	BDW 46, BDW 94B
BDT 64 AF		Si-P-Darl+Di	=BDT 64: Iso, 80/80V, >22W		17c	SOT-186	(BDW 94 C)[3]	17j	-
BDT 64 B		Si-P-Darl+Di	=BDT 64: 100/100V		17j	TO-220	BDW 94 C	17j	BDW 47, BDW 94C
BDT 64 BF		Si-P-Darl+Di	=BDT 64: Iso, 100/100V, >22W		17c	SOT-186	(BDW 94 C)[3]	17j	-
BDT 64 C		Si-P-Darl+Di	=BDT 64: 120/120V		17j	TO-220			-
BDT 64 CF		Si-P-Darl+Di	=BDT 64: Iso, 120/120V, >22W		17c	SOT-186			-
BDT 64 F		Si-P-Darl+Di	=BDT 64: Iso, >22W		17c	SOT-186	(BDW 94 C)[3]	17j	2SB1351
BDT 65	Phi	Si-N-Darl+Di	LF P, 60/60V, 12/20A, 125W, >10MHz, hFE>1000	{BDT64	17j	TO-220	BDW 93 C	17j	BDW 40, BDW 93A
BDT 65 A		Si-N-Darl+Di	=BDT 65: 80/80V		17j	TO-220	BDW 93 C	17j	BDW 41, BDW 93B
BDT 65 AF		Si-N-Darl+Di	=BDT 65: Iso, 80/80V, >22W		17c	SOT-186	(BDW 93 C)[3]	17j	2SC4063
BDT 65 B		Si-N-Darl+Di	=BDT 65: 100/100V		17j	TO-220	BDW 93 C	17j	BDW 42, BDW 93C
BDT 65 BF		Si-N-Darl+Di	=BDT 65: Iso, 100/100V, >22W		17c	SOT-186	(BDW 93 C)[3]	17j	2SC4063
BDT 65 C		Si-N-Darl+Di	=BDT 65: 120/120V		17j	TO-220			-
BDT 65 CF		Si-N-Darl+Di	=BDT 64: Iso, 120/120V, >22W		17c	SOT-186			-
BDT 65 F		Si-N-Darl+Di	=BDT 65: Iso, >22W		17c	SOT-186	(BDW 93 C)[3]	17j	2SC4063
BDT 81	Phi	Si-N	LF,S P, 60/60V, 15/20A, 125W, 10MHz, <1/2µs	{BDT82	17j	TO-220			BD 907
BDT 81 F		Si-N	=BDT 81: Iso, >21W		17c	SOT-186			2SD1964
BDT 82	Phi	Si-P	LF,S P, 60/60V, 15/20A, 125W, 20MHz, <1/2µs	{BDT81	17j	TO-220			BD 908
BDT 82 F		Si-P	=BDT 82: Iso, >21W		17c	SOT-186			-
BDT 83	Phi	Si-N	=BDT 81: 80/80V	{BDT84	17j	TO-220			BD 909
BDT 83 F		Si-N	=BDT 83: Iso, >21W		17c	SOT-186			2SD1964
BDT 84	Phi	Si-P	=BDT 82: 80/80V	{BDT83	17j	TO-220			BD 910
BDT 84 F		Si-P	=BDT 84: Iso, >21W		17c	SOT-186			-
BDT 85	Phi	Si-N	=BDT 81: 100/100V	{BDT86	17j	TO-220			BD 911
BDT 85 F		Si-N	=BDT 85: Iso, >21W		17c	SOT-186			2SD1964
BDT 86	Phi	Si-P	=BDT 82: 100/100V	{BDT85	17j	TO-220			BD 912
BDT 86 F		Si-P	=BDT 86: Iso, >21W		17c	SOT-186			-
BDT 87	Phi	Si-N	=BDT 81: 120/120V	{BDT88	17j	TO-220			-
BDT 87 F		Si-N	=BDT 87: Iso, >21W		17c	SOT-186			2SD1964
BDT 88	Phi	Si-P	=BDT 82: 120/120V	{BDT87	17j	TO-220			-
BDT 88 F		Si-P	=BDT 88: Iso, >21W		17c	SOT-186			-
BDT 91	Phi	Si-N	LF,S P, 60/60V, 10/20A, 90W, >4MHz	{BDT92	17j	TO-220	BD 809	17j	BD 743A, BD 807, BD 907
BDT 91 F		Si-N	=BDT 91: Iso, >20W		17c	SOT-186	(BD 809)[3]	17j	BDT 81F, 2SD1964
BDT 92	Phi	Si-P	LF,S P, 60/60V, 10/20A, 90W, >4MHz	{BDT91	17j	TO-220	BD 810	17j	BD 744A, BD 808, BD 908
BDT 92 F		Si-P	=BDT 92: Iso, >20W		17c	SOT-186	(BD 810)[3]	17j	BDT 82F
BDT 93	Phi	Si-N	=BDT 91: 80/80V	{BDT94	17j	TO-220	BD 809	17j	BD 743B, BD 809, BD 909

Original	Fabric.	Constr.	Info	Compl.	Fig.		JAEGER	Fig.	International
BDT 93 F		Si-N	=BDT 93: Iso, >20W		17c	SOT-186	(BD 809)[3]	17j	BDT 83F, 2SD1964
BDT 94	Phi	Si-P	=BDT 92: 80/80V	(BDT93	17j	TO-220	BD 810	17j	BD 744B, BD 810, BD 910
BDT 94 F		Si-P	=BDT 93: Iso, >20W		17c	SOT-186	(BD 810)[3]	17j	BDT 84F
BDT 95	Phi	Si-N	=BDT 91: 100/100V	(BDT96	17j	TO-220			BD 743C, BD 911
BDT 95 F		Si-N	=BDT 95: Iso, >20W		17c	SOT-186			BDT 85F, 2SD1964
BDT 96	Phi	Si-P	=BDT 92: 100/100V	(BDT95	17j	TO-220			BD 744C, BD 912
BDT 96 F		Si-P	=BDT 96: Iso, >20W		17c	SOT-186			BDT 86F
BDV									
BDV 10	Sie	Si-N	LF,S P, 120/70V, 5A, 26W(Tc=45°), >30MHz		17j	TO-220	2SC2334	17j	MJE 15028, 2SC2527, 2SD772
BDV 11	Sie	Si-N	=BDV 10: 140/90V		17j	TO-220	2SC2334	17j	MJE 15030, 2SD772
BDV 12	Sie	Si-N	=BDV 10: 120/90V		17j	TO-220	2SC2334	17j	MJE 15028, 2SC2527, 2SD772
BDV 13	Sie	Si-N-Darl	LF P, 45/45V, 4A, 36W, >3MHz, hFE=750...3000	(BDV14	17j	TO-220	BD 901	17j	BD 713, BDW 23, BDW 53, BDW 63
BDV 14	Sie	Si-P-Darl	LF P, 45/45V, 4A, 36W, >3MHz, hFE=750...3000	(BDV13	17j	TO-220	BD 902	17j	BD 714, BDW 24, BDW 54, BDW 64
BDV 15	Sie	Si-N-Darl	=BDV 13: 60/60V	(BDV16	17j	TO-220	BD 901	17j	BD 715, BDW 23A, BDW 53A, BDW 63A
BDV 16	Sie	Si-P-Darl	=BDV 14: 60/60V	(BDV15	17j	TO-220	BD 902	17j	BD 716, BDW 24A, BDW 54A, BDW 64A
BDV 17	Sie	Si-N-Darl	=BDV 13: 80/80V	(BDV18	17j	TO-220	BD 901	17j	BD 717, BDW 23B, BDW 53B, BDW 63B
BDV 18	Sie	Si-P-Darl	=BDV 14: 80/80V	(BDV17	17j	TO-220	BD 902	17j	BD 718, BDW 24B, BDW 54B, BDW 64B
BDV 33	Sie	Si-N	LF P, 45/45V, 5A, 40W, >3MHz, sat<0,8V(6A)	(BDV34	17j	TO-220	(BD 243 C)[17]	17j	2SC3258, 2SD1236L, (BD 243, BD 539A,++)[17]
BDV 34	Sie	Si-P	LF P, 45/45V, 5A, 40W, >3MHz, sat<0.8V(6A)	(BDV33	17j	TO-220	(BD 244 C)[17]	17j	2SA1293, 2SB920L, (BD 244, BD 540A,++)[17]
BDV 35	Sie	Si-N	=BDV 33: 60/60V	(BDV36	17j	TO-220	(BD 243 C)[17]	17j	2SC3258, 2SD1236L, (BD 243A, BD 539A,++)[17]
BDV 36	Sie	Si-P	=BDV 34: 60/60V	(BDV35	17j	TO-220	(BD 244 C)[17]	17j	2SA1293, 2SB920L, (BD 244A, BD 540A,++)[17]
BDV 37	Sie	Si-N	=BDV 33: 80/80V	(BDV38	17j	TO-220	(BD 243 C)[17]	17j	2SC3258, 2SD1236L, (BD 243B, BD 539B,++)[17]
BDV 38	Sie	Si-P	=BDV 34: 80/80V	(BDV37	17j	TO-220	(BD 244 C)[17]	17j	2SA1293, 2SB920L, (BD 244B, BD 540B,++)
BDV 45	Sie	Si-N-Darl	LF P, 60/60V, 8A, 62,5W, >3MHz, hFE>750	(BDV46	17j	TO-220	BD 901	17j	BD 645, BD 897, BDW 73A, BDX 53A, ++
BDV 46	Sie	Si-P-Darl	LF P, 60/60V, 8A, 62,5W, >3MHz, hFE>750	(BDX45	17j	TO-220	BD 902	17j	BD 646, BD 898, BDW 74A, BDX 54A, ++
BDV 47	Sie	Si-N-Darl	=BDV 45: 80/80V	(BDV48	17j	TO-220	BD 901	17j	BD 647, BD 899, BDW 73B, BDX 53B, ++
BDV 48	Sie	Si-P-Darl	=BDV 46: 80/80V	(BDV47	17j	TO-220	BD 902	17j	BD 648, BD 900, BDW 74B, BDX 54B, ++
BDV 49	Sie	Si-N-Darl	=BDV 45: 100/100V	(BDV50	17j	TO-220	BD 901	17j	BD 649, BD 901, BDW 73C, BDX 53C, ++
BDV 50	Sie	Si-P-Darl	=BDV 46: 100/100V	(BDV49	17j	TO-220	BD 902	17j	BD 650, BD 902, BDW 74C, BDX 54C, ++
BDV 64	Mot,Phi,Tho	Si-P-Darl+Di	LF P, 60/60V, 12/20A, 125W, hFE>1000	(BDV65	18j	SOT-93	BDW 84 C	18j	BDV 66, BDW 84A
BDV 64 A		Si-P-Darl+Di	=BDV 64: 80/80V		18j	SOT-93	BDW 84 C	18j	BDV 66A, BDW 84B
BDV 64 AF		Si-P-Darl+Di	=BDV 64A: Iso, >31W		16c	SOT-199	(BDW 84 C)[3]	18j	2SB1382, 2SB1448
BDV 64 B		Si-P-Darl+Di	=BDV 64: 100/100V		18j	SOT-93	BDW 84 C	18j	BDV 66B, BDW 84C
BDV 64 BF		Si-P-Darl+Di	=BDV 64B: Iso, >31W		16c	SOT-199	(BDW 84 C)[3]	18j	2SB1382, 2SB1448
BDV 64 C		Si-P-Darl+Di	=BDV 64: 120/120V		18j	SOT-93			BDV 66C, BDW 84D
BDV 64 CF		Si-P-Darl+Di	=BDV 64C: Iso, >31W		16c	SOT-199			2SB1382
BDV 64 F		Si-P-Darl+Di	=BDV 64: Iso, >31W		16c	SOT-199	(BDW 84 C)[3]	18j	2SB1352, 2SB1382, 2SB1448
BDV 65	Mot,Phi,Tho	Si-N-Darl+Di	LF P, 60/60V, 12/20A, 125W, hFE>1000	(BDV64	18j	SOT-93	BDW 83 C	18j	BDV 67, BDW 83A
BDV 65 A		Si-N-Darl+Di	=BDV 65: 80/80V		18j	SOT-93	BDW 83 C	18j	BDV 67A, BDW 83B
BDV 65 AF		Si-N-Darl+Di	=BDV 65A: Iso, >31W		16c	SOT-199	(BDW 83 C)[3]	18j	2SD2082
BDV 65 B		Si-N-Darl+Di	=BDV 65: 100/100V		18j	SOT-93	BDW 83 C	18j	BDV 67B, BDW 83C
BDV 65 BF		Si-N-Darl+Di	=BDV 65B: Iso, >31W		16c	SOT-199	(BDW 83 C)[3]	18j	2SD2082
BDV 65 C		Si-N-Darl+Di	=BDV 65: 120/120V		18j	SOT-93			BDV 67C, BDW 83D
BDV 65 CF		Si-N-Darl+Di	=BDV 65C: Iso, >31W		16c	SOT-199			2SD2082
BDV 65 F		Si-N-Darl+Di	=BDV 65: Iso, >31W		16c	SOT-199	(BDW 83 C)[3]	18j	2SD2082
BDV 66	Aeg,Phi,Tho	Si-P-Darl+Di	LF P, 60/60V, 16/20A, 200W, hFE>1000	(BDV67	18j	SOT-93	BDW 84 C	18j	BDW 84A, 2SB1079, 2SB1383, 2SB1494
BDV 66 A		Si-P-Darl+Di	=BDV 66: 100/80V		18j	SOT-93	BDW 84 C	18j	BDW 84C, 2SB1079, 2SB1383, 2SB1494
BDV 66 AF		Si-P-Darl+Di	=BDV 66A: Iso, >35W		16c	SOT-199	(BDW 84 C)[3]	18j	2SB1382, 2SB1448
BDV 66 B		Si-P-Darl+Di	=BDV 66: 120/100V		18j	SOT-93			BDW 84D, 2SB1383, 2SB1494
BDV 66 BF		Si-P-Darl+Di	=BDV 66B: Iso, >35W		16c	SOT-199			2SB1382
BDV 66 C		Si-P-Darl+Di	=BDV 66: 140/120V		18j	SOT-93			-
BDV 66 CF		Si-P-Darl+Di	=BDV 66C: Iso, >35W		16c	SOT-199			-
BDV 66 D		Si-P-Darl+Di	=BDV 66: 160/150V		18j	SOT-93			-
BDV 66 DF		Si-P-Darl+Di	=BDV 66D: Iso, >35W		16c	SOT-199			-
BDV 67	Aeg,Phi,Tho	Si-N-Darl+Di	LF P, 60/60V, 16/20A, 200W, hFE>1000	(BDV66	18j	SOT-93	BDW 83 C	18j	BDW 83A, 2SD1559, 2SD1597, 2SD2256
BDV 67 A		Si-N-Darl+Di	=BDV 67: 100/80V		18j	SOT-93	BDW 83 C	18j	BDW 83C, 2SD1559, 2SD1597, 2SD2256
BDV 67 AF		Si-N-Darl+Di	=BDV 67A: Iso, >35W		16c	SOT-199	(BDW 83 C)[3]	18j	2SD2082
BDV 67 B		Si-N-Darl+Di	=BDV 67: 120/100V		18j	SOT-93			BDW 83D, 2SD1597, 2SD2083, 2SD2256
BDV 67 BF		Si-N-Darl+Di	=BDV 67B: Iso, >35W		16c	SOT-199			2SD2082
BDV 67 C		Si-N-Darl+Di	=BDV 67: 140/120V		18j	SOT-93			2SD1297
BDV 67 CF		Si-N-Darl+Di	=BDV 67C: Iso, >35W		16c	SOT-199			-
BDV 67 D		Si-N-Darl+Di	=BDV 67: 160/150V		18j	SOT-93			-
BDV 67 DF		Si-N-Darl+Di	=BDV 67D: Iso, >35W		16c	SOT-199			-
BDV 91	Phi	Si-N	LF,S P, 60/60V, 10/20A, 100W, >3MHz	(BDV92	18j	SOT-93	BD 245 C	18j	BD 245A, BD 745A, 2SD1187
BDV 92	Phi	Si-P	LF,S P, 60/60V, 10/20A, 100W, >4MHz	(BDV91	18j	SOT-93	BD 246 C	18j	BD 246A, BD 746A, 2SB922L, 2SB1230
BDV 93	Phi	Si-N	=BDV 91: 80/80V	(BDV94	18j	SOT-93	BD 245 C	18j	BD 245B, BD 745B, 2SD1187
BDV 94	Phi	Si-P	=BDV 92: 80/80V	(BDV93	18j	TO-3P	BD 246 C	18j	BD 246B, BD 746B, 2SB922L, 2SB1230
BDV 95	Phi	Si-N	=BDV 91: 100/100V	(BDV96	18j	SOT-93	BD 245 C	18j	BD 245C, BD 745C, 2SD1187
BDV 96	Phi	Si-P	=BDV 92: 100/100V	(BDV95	18j	SOT-93	BD 246 C	18j	BD 246C, BD 746C, 2SB922L, 2SB1230
BDW									
BDW		Z-Di	=SM 15T 15C (SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BDW 10(A)	Mot	Si-N	LF,S P, 140/100V, 15A, 180W, >1MHz		23a	TO-3	MJ 15015	23a	BDW 30, MJ 15015, 2SC1585, 2SC2607...08,+
BDW 12(A)	Mot	Si-N	=BDW 10: 160/120V		23a	TO-3	MJ 15015	23a	BDW 34, MJ 15015, 2SC1585, 2SC2607...08,+
BDW 14(A)	Mot	Si-N	=BDW 10: 180/140V		23a	TO-3	MJ 15015	23a	BDW 34, MJ 15015, 2SC1585, 2SC2607...08,+
BDW 16(A)	Mot	Si-N	=BDW 10: 200/160V		23a	TO-3	MJ 15015	23a	BDW 36, MJ 15015, 2SC1585, 2SC2607...08,+
BDW 21	Sgs	Si-N	LF,S P, 45/45V, 10/15A, 90W, >3MHz	(BDW22	23a	TO-3	BD 245 C	18j	BD 245, BD 311, BD 315, BDW 51, ++
BDW 21 A		Si-N	=BDW 21: 60/60V		23a	TO-3	BD 245 C	18j	BD 245A, BD 311, BD 315, BDW 51A, ++
BDW 21 B		Si-N	=BDW 21: 80/80V		23a	TO-3	BD 245 C	18j	BD 245B, BD 313, BD 315, BDW 51B, ++
BDW 21 C		Si-N	=BDW 21: 100/100V		23a	TO-3	BD 245 C	18j	BD 245C, BD 317, BDW 51C, ++
BDW 22	Sgs	Si-P	LF,S P, 45/45V, 10/15A, 90W, >3MHz	(BDW21	23a	TO-3	BD 246 C	18j	BD 246, BD 312, BD 316, BDW 52, ++
BDW 22 A		Si-P	=BDW 22: 60/60V		23a	TO-3	BD 246 C	18j	BD 246A, BD 312, BD 316, BDW 52A, ++
BDW 22 B		Si-P	=BDW 22: 80/80V		23a	TO-3	BD 246 C	18j	BD 246B, BD 314, BD 316, BDW 52B, ++
BDW 22 C		Si-P	=BDW 22: 100/100V		23a	TO-3	BD 246 C	18j	BD 246C, BD 316, BDW 52C, ++
BDW 23	Sgs	Si-N-Darl+Di	LF P, 45/45V, 6/8A, 50W, hFE>750	(BDW24	17j	TO-220	BD 901	17j	BD 643, BD 895, BDW 63, BDX 53, ++
BDW 23 A		Si-N-Darl+Di	=BDW 23: 60/60V		17j	TO-220	BD 901	17j	BD 645, BD 897, BDW 63A, BDX 53A, ++
BDW 23 B		Si-N-Darl+Di	=BDW 23: 80/80V		17j	TO-220	BD 901	17j	BD 647, BD 899, BDW 63B, BDX 53B, ++
BDW 23 C		Si-N-Darl+Di	=BDW 23: 100/100V		17j	TO-220	BD 901	17j	BD 649, BD 901, BDW 63C, BDX 53C, ++
BDW 24	Sgs	Si-P-Darl+Di	LF P, 45/45V, 6/8A, 50W, hFE>750	(BDW23	17j	TO-220	BD 902	17j	BD 644, BD 896, BDW 64, BDX 54, ++
BDW 24 A		Si-P-Darl+Di	=BDW 24: 60/60V		17j	TO-220	BD 902	17j	BD 646, BD 898, BDW 64A, BDX 54A, ++
BDW 24 B		Si-P-Darl+Di	=BDW 24: 80/80V		17j	TO-220	BD 902	17j	BD 648, BD 900, BDW 64B, BDX 54B, ++
BDW 24 C		Si-P-Darl+Di	=BDW 24: 100/100V		17j	TO-220	BD 902	17j	BD 650, BD 902, BDW 64C, BDX 54C, ++

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BDW 25	Sie	Si-N	P, 130/125V, 5/5A, 26W(Tc=45°), 30MHz, <0,5/2µs		22a	SOT-9	(BU 406)	17j	BDX 25, BDV 11, MJE 15030, 2SD772
BDW 26	Tra	Diac	Ub=22…30V, Ib<0,8mA, Itsm=1A		31	DO-7			-
BDW 30	Mot	Si-N	LF,S P, 140/100V, 30A, 250W, >1MHz		23a	TO-3			2N6276…6277
BDW 32	Mot	Si-N	=BDW 30: 160/120V		23a	TO-3			2N6276…6277
BDW 32	Tra	Diac	=BDW 26: Ub=28…36V		31	DO-7			A9903, D32
BDW 34	Mot	Si-N	=BDW 30: 180/140V		23a	TO-3			2N6277
BDW 36	Mot	Si-N	=BDW 30: 200/160V		23a	TO-3			-
BDW 38	Tra	Diac	=BDW 26: Ub=34…42V		31	DO-7			-
BDW 39	Mot	Si-N-Darl	LF P, 45/45V, 15A, 85W, >4MHz, hFE>1000	{BDW44	17j	TO-220	(BDW 93 C)[7]	17j	-
BDW 40	Mot	Si-N-Darl	=BDW 39: 60/60V	{BDW45	17j	TO-220	(BDW 93 C)[7]	17j	-
BDW 41	Mot	Si-N-Darl	=BDW 39: 80/80V	{BDW46	17j	TO-220	(BDW 93 C)[7]	17j	-
BDW 42	Mot	Si-N-Darl	=BDW 39: 100/100V	{BDW47	17j	TO-220	(BDW 93 C)[7]	17j	-
BDW 44	Mot	Si-P-Darl	LF P, 45/45V, 15A, 85W, >4MHz, hFE>1000	{BDW39	17j	TO-220	(BDW 94 C)[7]	17j	-
BDW 45	Mot	Si-P-Darl	=BDW 44: 60/60V	{BDW40	17j	TO-220	(BDW 94 C)[7]	17j	-
BDW 46	Mot	Si-P-Darl	=BDW 44: 80/80V	{BDW41	17j	TO-220	(BDW 94 C)[7]	17j	-
BDW 47	Mot	Si-P-Darl	=BDW 44: 100/100V	{BDW42	17j	TO-220	(BDW 94 C)[7]	17j	-
BDW 51	Sgs	Si-N	LF,S P, 45/45V, 15/20A, 125W, >3MHz	{BDW52	23a	TO-3	BD 317	23a	BD 249, BD 315, BDY 55, 2N5629…31, ++
BDW 51 A		Si-N	=BDW 51: 60/60V		23a	TO-3	BD 317	23a	BD 249A, BD 315, BDY 55, 2N5629…31, ++
BDW 51 B		Si-N	=BDW 51: 80/80V		23a	TO-3	BD 317	23a	BD 249B, BD 315, BDY 55, 2N5629…31, ++
BDW 51 C		Si-N	=BDW 51: 100/100V		23a	TO-3	BD 317	23a	BD 249C, BD 317, BDY 55, 2N5629…31, ++
BDW 52	Sgs	Si-P	LF,S P, 45/45V, 15/20A, 125W, >3MHz		23a	TO-3	BD 318	23a	BD 250, BD 316, 2N6029…6031, ++
BDW 52 A		Si-P	=BDW 52: 60/60V		23a	TO-3	BD 318	23a	BD 250A, BD 316, 2N6029…6031, ++
BDW 52 B		Si-P	=BDW 52: 80/80V		23a	TO-3	BD 318	23a	BD 250B, BD 316, 2N6029…6031, ++
BDW 52 C		Si-P	=BDW 52: 100/100V		23a	TO-3	BD 318	23a	BD 250C, BD 318, 2N6029…6031, ++
BDW 53	Tix	Si-N-Darl+Di	LF P, 45/45V, 4A, 40W, >1MHz, hFE=750…20k	{BDW54	17j	TO-220	BD 901	17j	BD 713, BDW 23, BDW 63, ++
BDW 53 A		Si-N-Darl+Di	=BDW 53: 60/60V		17j	TO-220	BD 901	17j	BD 715, BDW 23A, BDW 63A, ++
BDW 53 B		Si-N-Darl+Di	=BDW 53: 80/80V		17j	TO-220	BD 901	17j	BD 717, BDW 23B, BDW 63B, ++
BDW 53 C		Si-N-Darl+Di	=BDW 53: 100/100V		17j	TO-220	BD 901	17j	BDW 23C, BDW 63C
BDW 53 D		Si-N-Darl+Di	=BDW 53: 120/120V		17j	TO-220			BDW 63D, 2SD1147
BDW 54	Tix	Si-P-Darl+Di	LF P, 45/45V, 4A, 40W, >1MHz, hFE=750…20k	{BDW53	17j	TO-220	BD 902	17j	BD 714, BDW 24, BDW 64, ++
BDW 54 A		Si-P-Darl+Di	=BDW 54: 60/60V		17j	TO-220	BD 902	17j	BD 716, BDW 24A, BDW 64A, ++
BDW 54 B		Si-P-Darl+Di	=BDW 54: 80/80V		17j	TO-220	BD 902	17j	BD 718, BDW 24B, BDW 64B, ++
BDW 54 C		Si-P-Darl+Di	=BDW 54: 100/100V		17j	TO-220	BD 902	17j	BDW 24C, BDW 64C
BDW 54 D		Si-P-Darl+Di	=BDW 54: 120/120V		17j	TO-220			BDW 64D
BDW 55	Phi	Si-N	=BD 135: hi-rel Version		14h	TO-126	›BD 135		›BD 135
BDW 56	Phi	Si-P	=BD 136: hi-rel Version		14h	TO-126	›BD 136		›BD 136
BDW 57	Phi	Si-N	=BD 137: hi-rel Version		14h	TO-126	›BD 137		›BD 137
BDW 58	Phi	Si-P	=BD 138: hi-rel Version		14h	TO-126	›BD 138		›BD 138
BDW 59	Phi	Si-N	=BD 139: hi-rel Version		14h	TO-126	›BD 139		›BD 139
BDW 60	Phi	Si-P	=BD 140: hi-rel Version		14h	TO-126	›BD 140		›BD 140
BDW 63	Tix	Si-N-Darl+Di	LF P, 45/45V, 6A, 60W, >1MHz, hFE=750…20k	{BDW64	17j	TO-220	BD 901	17j	BD 643, BD 895, BDW 23, BDX 53, ++
BDW 63 A	Tix	Si-N-Darl+Di	=BDW 63: 60/60V		17j	TO-220	BD 901	17j	BD 645, BD 897, BDW 23A, BDX 53A, ++
BDW 63 B		Si-N-Darl+Di	=BDW 63: 80/80V		17j	TO-220	BD 901	17j	BD 647, BD 899, BDW 23B, BDX 53B, ++
BDW 63 C		Si-N-Darl+Di	=BDW 63: 100/100V		17j	TO-220	BD 901	17j	BD 649, BD 901, BDW 23C, BDX 53C, ++
BDW 63 D		Si-N-Darl+Di	=BDW 63: 120/120V		17j	TO-220			BD 651, BDT 21, BDX 53E
BDW 64	Tix	Si-P-Darl+Di	LF P, 45/45V, 6A, 60W, >1MHz, hFE=750…20k	{BDW63	17j	TO-220	BD 902	17j	BD 644, BD 896, BDW 24, BDX 54, ++
BDW 64 A		Si-P-Darl+Di	=BDW 64: 60/60V		17j	TO-220	BD 902	17j	BD 646, BD 898, BDW 24A, BDX 54A, ++
BDW 64 B		Si-P-Darl+Di	=BDW 64: 80/80V		17j	TO-220	BD 902	17j	BD 648, BD 900, BDW 24B, BDX 54B, ++
BDW 64 C		Si-P-Darl+Di	=BDW 64: 100/100V		17j	TO-220	BD 902	17j	BD 650, BD 902, BDW 24C, BDX 54C, ++
BDW 64 D		Si-P-Darl+Di	=BDW 64: 120/120V		17j	TO-220			BD 652, BDT 20, BDX 54E
BDW 69	Tho	MOS-N-FET-e	VFET, LF P, 40/15V, 2/3A, 12,5W, on<2Ω, <10/10ns		13e	TO-202			-
BDW 70	Tho	MOS-N-FET-e	=BDW 69: 60/15V		13e	TO-202			-
BDW 71	Tho	MOS-N-FET-e	=BDW 69: 90/15V		13e	TO-202			-
BDW 73	Tix	Si-N-Darl+Di	LF P, 45/45V, 8A, 80W, >1MHz, hFE=750…20k	{BDW74	17j	TO-220	BD 901	17j	BD 643, BD 895, BDX 33, BDX 53
BDW 73 A		Si-N-Darl+Di	=BDW 73: 60/60V		17j	TO-220	BD 901	17j	BD 645, BD 897, BDX 33A, BDX 53A
BDW 73 B		Si-N-Darl+Di	=BDW 73: 80/80V		17j	TO-220	BD 901	17j	BD 647, BD 899, BDX 33B, BDX 53B
BDW 73 C		Si-N-Darl+Di	=BDW 73: 100/100V		17j	TO-220	BD 901	17j	BD 649, BD 901, BDX 33C, BDX 53C
BDW 73 D		Si-N-Darl+Di	=BDW 73: 120/120V		17j	TO-220			BD 651, BDX 33D, BDX 53E
BDW 74	Tix	Si-P-Darl+Di	LF P, 45/45V, 8A, 80W, >1MHz, hFE=750…20k	{BDW73	17j	TO-220	BD 902	17j	BD 644, BD 896, BDX 33, BDX 53
BDW 74 A		Si-P-Darl+Di	=BDW 74: 60/60V		17j	TO-220	BD 902	17j	BD 646, BD 898, BDX 33A, BDX 53A
BDW 74 B		Si-P-Darl+Di	=BDW 74: 80/80V		17j	TO-220	BD 902	17j	BD 648, BD 900, BDX 33B, BDX 53B
BDW 74 C		Si-P-Darl+Di	=BDW 74: 100/100V		17j	TO-220	BD 902	17j	BD 650, BD 902, BDX 33C, BDX 53C
BDW 74 D		Si-P-Darl+Di	=BDW 74: 120/120V		17j	TO-220			BD 652, BDX 33D, BDX 53E
BDW 83	Sgs,Tix	Si-N-Darl+Di	LF P, 45/45V, 15/40A, 150W, >1MHz, hFE>750	{BDW84	18j	TO-3P	BDW 83 C	18j	BDV 67, 2SD1559, 2SD2083, 2SD2256
BDW 83 A		Si-N-Darl+Di	=BDW 83: 60/60V		18j	TO-3P	BDW 83 C	18j	BDV 67, 2SD1559, 2SD2083, 2SD2256
BDW 83 B		Si-N-Darl+Di	=BDW 83: 80/80V		18j	TO-3P	BDW 83 C	18j	BDV 67A, 2SD1559, 2SD2083, 2SD2256
BDW 83 C		Si-N-Darl+Di	=BDW 83: 100/100V		18j	TO-3P	BDW 83 C	18j	BDV 67A, 2SD1559, 2SD2083, 2SD2256
BDW 83 D		Si-N-Darl+Di	=BDW 83: 120/120V		18j	TO-3P			BDV 67B, 2SD2083, 2SD2256
BDW 84	Sgs,Tix	Si-P-Darl+Di	LF P, 45/45V, 15/40A, 150W, >1MHz, hFE>750	{BDW83	18j	TO-3P	BDW 84 C	18j	BDV 66, 2SB1079, 2SB1383, 2SB1494
BDW 84 A		Si-P-Darl+Di	=BDW 84: 60/60V		18j	TO-3P	BDW 84 C	18j	BDV 66, 2SB1079, 2SB1383, 2SB1494
BDW 84 B		Si-P-Darl+Di	=BDW 84: 80/80V		18j	TO-3P	BDW 84 C	18j	BDV 66A, 2SB1079, 2SB1383, 2SB1494
BDW 84 C		Si-P-Darl+Di	=BDW 84: 100/100V		18j	TO-3P	BDW 84 C	18j	BDV 66A, 2SB1079, 2SB1383, 2SB1494
BDW 84 D		Si-P-Darl+Di	=BDW 84: 120/120V		18j	TO-3P			BDV 66B, 2SB1383, 2SB1494
BDW 91	Sgs	Si-N-Darl+Di	LF,S, 180/180V, 4A, 10W(Tc=25°), 20MHz, hFE=3k>1k		2a	TO-39			(2SC3186, 2SD1121)[4]
BDW 92	Sgs	Si-P-Darl+Di	LF,S, 180/180V, 4A, 10W(Tc=25°), 20MHz, hFE=3k>1k		2a	TO-39			-
BDW 93	Sgs	Si-N-Darl+Di	LF P, 45/45V, 12/15A, 80W, >20MHz, hFE>750	{BDW94	17j	TO-220	BDW 93 C	17j	BDT 65, BDW 39
BDW 93 A		Si-N-Darl+Di	=BDW 93: 60/60V		17j	TO-220	BDW 93 C	17j	BDT 65, BDW 40
BDW 93 B		Si-N-Darl+Di	=BDW 93: 80/80V		17j	TO-220	BDW 93 C	17j	BDT 65A, BDW 41
BDW 93 C		Si-N-Darl+Di	=BDW 93: 100/100V		17j	TO-220	BDW 93 C	17j	BDT 65B, BDW 42
BDW 93 CFI		Si-N-Darl+Di	=BDW 93C: Iso, 40W		17c	TO-220Iso	(BDW 93C)[3]	17j	BDT 65BF…CF, 2SC 4063
BDW 94	Sgs	Si-P-Darl+Di	LF P, 45/45V, 12/15A, 80W, >20MHz, hFE>750	{BDW93	17j	TO-220	BDW 94 C	17j	BDT 64, BDW 44
BDW 94 A		Si-P-Darl+Di	=BDW 94: 60/60V		17j	TO-220	BDW 94 C	17j	BDT 64, BDW 45
BDW 94 B		Si-P-Darl+Di	=BDW 94: 80/80V		17j	TO-220	BDW 94 C	17j	BDT 64A, BDW 46
BDW 94 C		Si-P-Darl+Di	=BDW 94: 100/100V		17j	TO-220	BDW 94 C	17j	BDT 64B, BDW 47
BDW 94 CFI		Si-P-Darl+Di	=BDW 94C: Iso, 40W		17c	TO-220Iso	(BDW 94C)[3]	17j	BDT 64BF…CF
BDX									
BDX		Z-Di	=SM 15T 15CA(SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T….
BDX 10(C,H)	Sgs	Si-N	LF,S P, 100/60V, 15A, 117W, >0,8MHz, (=2N3055) C=80/70V, H=100/90V		23a	TO-3	2N3055	23a	BD 317, BD 745C, BDW 51C, 2N3055, ++
BDX 11	Sgs	Si-N	LF,S P, 160/140V, 10/15A, 117W, >0,8MHz, (=2N3442)		23a	TO-3	2SD1047	18j	BDW 12, 2N3442, 2SD733, 2SD1047, 2SD1703
BDX 12	Sgs	Si-N	LF,S P, 140/120V, 10/15A, 100W, >0,8MHz, (=2N4347)		23a	TO-3	2SD1047	18j	BDW 10, 2N5631, 2SC1584, 2SD1047, ++
BDX 13	Sgs	Si-N	LF,S P, 50/40V, 15A, 117W, >0,8MHz		23a	TO-3	BD 317	23a	BD 315, BD 745, BDW 51A, 2N5881, ++

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BDX 14	Tho,Tix	Si-P	LF,S P, 90/55V, 4A, 29W, >4MHz	{2N3054	22a	TO-66	BD 244 C	17j	BD 244B, BD 954, 2N5954, 2SB550, ++
BDX 15	Tix	Si-P	LF,S P, -/70V, 10A, 117W, >0,8MHz	{2N3055	23a	TO-3	BD 318	23a	BD 246B, BD 314, BDW 22A, 2N5875, ++
BDX 16	Tho	Si-P	LF,S P, 160/140V, 3/4A, 25W, 4MHz		22a	TO-66	(2SB861)[7]	17j	BD 242D, BUX 66, MJE 5850, 2SB720
BDX 18	Rca,Tho	Si-P	LF,S P, 100/60V, 15A, 117W, 4MHz	{2N3055	23a	TO-3	BD 318	23a	BD 318, BD 746C, BDW 52C, MJ 2955, ++
BDX 18 N		Si-P	=BDX 18: 70/60V		23a	TO-3	BD 318	23a	BD 316, BD 746B, BDW 52B, MJ 2955, ++
BDX 20	Tho	Si-P	LF,S P, 160/140V, 10A, 117W, >4MHz		23a	TO-3	2SB817	18j	BD 245D, 2SA1147, 2SB600, 2SB697, 2SB817
BDX 22	Sgs	Si-N	LF,S P, 160/140V, 10/15A, 37,5W, >0,8MHz		22a	SOT-9			BD 743F, BUV 27, 2SC2867, 2SC4330
BDX 23	Rca,Sgs	Si-N	LF,S P, 95V, 15A, 117W, >0,8MHz		23a	TO-3	BD 317	23a	BD 317, BD 745C, BDW 51C, 2N3055, ++
BDX 24	Rca,Sgs	Si-N	LF,S P, 50/40V, 4A, 29W, >0,8MHz		22a	TO-66	BD 243 C	17j	BD 243, BD 535, 2N4231A, 2N6374, ++
BDX 25	Sie	Si-N	S P, 130/125V, 5/10A, 34W(Tc=45°), 30MHz, <0,5/2µs		22a	SOT-9	(BU 406)	17j	BDW 25, BDV 11, MJE 15030, 2SD772
BDX 26	Sie	Si-P	LF,S P, 40/40V, 5A, 40W, >30MHz		23a	TO-3	BD 246 C	18j	BD 312, BD 246, 2SA1185, 2SA1292, ++
BDX 27	Sie	Si-P	S P, 40/40V, 5/7A, 50W(Tc=45°), 50MHz, <0,5/2µs		22a	SOT-9	BD 244 C	17j	BD 244, BD 948, 2SA1012, 2SA1289, ++
BDX 28	Sie	Si-P	=BDX 27: 60/60V		22a	SOT-9	BD 244 C	17j	BD 244A, BD 950, 2SA1012, 2SA1289, ++
BDX 29	Sie	Si-P	=BDX 27: 80/80V		22a	SOT-9	BD 244 C	17j	BD 244B, BD 952, MJE 15029, 2SA1289, ++
BDX 30	Sie	Si-P	=BDX 27: 125/125V		22a	SOT-9	(BD 244 C)[7]	17j	MJE 15031, 2SB869
BDX 31	Tix	Si-N	TV-HA, 2200V, 4/5A, 40W, sat<5V(3.5A)		23a	TO-3			2SC2125, 2SD621, 2SD838
BDX 32	Tix	Si-N	=BDX 31: 1700V		23a	TO-3	2SC3026	23a	2SC3026, 2SD784…785, 2SD1434
BDX 33	Rca,Tho,++	Si-N-Darl+Di	LF P, 45/45V, 10A, 70W, >20MHz, hFE>750	{BDX34	17j	TO-220	BDW 93 C	17j	BDT 63, BDT 65, BDW 93
BDX 33 A		Si-N-Darl+Di	=BDX 33: 60/60V		17j	TO-220	BDW 93 C	17j	BDT 63, BDT 65, BDW 93A
BDX 33 B		Si-N-Darl+Di	=BDX 33: 80/80V		17j	TO-220	BDW 93 C	17j	BDT 63A, BDT 65A, BDW 93B
BDX 33 C		Si-N-Darl+Di	=BDX 33: 100/100V		17j	TO-220	BDW 93 C	17j	BDT 63B, BDT 65B, BDW 93C
BDX 33 D		Si-N-Darl+Di	=BDX 33: 120/120V		17j	TO-220	2SD1756	17j	BDT 63C, BDT 65C, 2SD1126, 2SD 1607
BDX 33 E		Si-N-Darl+Di	=BDX 33: 140/140V		17j	TO-220	2SD1756	17j	2SD1500, 2SD1756
BDX 34	Rca,Tho,++	Si-P-Darl+Di	LF P, 45/45V, 10A, 70W, >20MHz, hFE>750	{BDX33	17j	TO-220	BDW 94 C	17j	BDT 62, BDT 64, BDW 94
BDX 34 A		Si-P-Darl+Di	=BDX 34: 60/60V		17j	TO-220	BDW 94 C	17j	BDT 62, BDT 64, BDW 94A
BDX 34 B		Si-P-Darl+Di	=BDX 34: 80/80V		17j	TO-220	BDW 94 C	17j	BDT 62A, BDT 64A, BDW 94B
BDX 34 C		Si-P-Darl+Di	=BDX 34: 100/100V		17j	TO-220	BDW 94 C	17j	BDT 62B, BDT 64B, BDW 94C
BDX 34 D		Si-P-Darl+Di	=BDX 34: 120/120V		17j	TO-220			BDT 62C, BDT 64C, 2SB1107
BDX 35	Phi	Si-N	LF,S P, 100/60V, 5/10A, 15W(Tc=75°), 100MHz		14h	TO-126			-
BDX 36	Phi	Si-N	=BDX 35: 120/60V		14h	TO-126			-
BDX 37		Si-N	=BDX 35: 120/80V		14h	TO-126			-
BDX 40	Sgs	Si-N	LF,S P, 100/60V, 20/30A, 150W, >0,8MHz, (=2N3772)		23a	TO-3			BDY 29, MJ 802, 2N3772, 2SD797
BDX 41	Sgs	Si-N	LF,S P, 50/40V, 30/30A, 150W, >0,8MHz, (=2N3771)		23a	TO-3			BDY 29, MJ 802, 2N3771, 2SD630
BDX 42	Phi	Si-N-Darl+Di	LF P, 60/45V, 1/2A, 5W(Tc=100°), 350MHz, hFE>2k		14h	TO-126	(BD 679)[8]	14h	-
BDX 43	Phi	Si-N-Darl+Di	=BDX 42: 80/60V	{BDX46	14h	TO-126	(BD 679)[8]	14h	-
BDX 44	Phi	Si-N-Darl+Di	=BDX 42: 100/80V	{BDX47	14h	TO-126	(BD 679)[8]	14h	-
BDX 45	Phi	Si-P-Darl+Di	LF P, 60/45V, 1/2A, 5W(Tc=100°), 350MHz, hFE>2k		14h	TO-126	(BD 680)[8]	14h	-
BDX 46	Phi	Si-P-Darl+Di	=BDX 45: 80/80V	{BDX42	14h	TO-126	(BD 680)[8]	14h	-
BDX 47		Si-P-Darl+Di	=BDX 45: 100/100V	{BDX43	14h	TO-126	(BD 680)[8]	14h	-
BDX 50	Sgs	Si-N	LF,S P, 160/140V, 16/30A, 150W, >0,8MHz, (=2N3773)		23a	TO-3	MJ 15015	23a	BD 249D, BD 745E, 2N3773, 2SC2608
BDX 51	Sgs	Si-N	LF,S P, 140/120V, 10/30A, 120W, >0,8MHz, (=2N4348)		23a	TO-3	MJ 15015	23a	BD745E, BDW 10, 2N4348, 2N5634, 2SD425++
BDX 53	Rca,Tho,++	Si-N-Darl+Di	LF P, 45/45V, 8/12A, 60W, 20MHz, hFE>750	{BDX54	17j	TO-220	BD 901	17j	BD 643, BD 895, BDW 73, BDX 33
BDX 53 A		Si-N-Darl+Di	=BDX 53: 60/60V		17j	TO-220	BD 901	17j	BD 645, BD 897, BDW 73A, BDX 33A
BDX 53 B		Si-N-Darl+Di	=BDX 53: 80/80V		17j	TO-220	BD 901	17j	BD 647, BD 899, BDW 73B, BDX 33B
BDX 53 C		Si-N-Darl+Di	=BDX 53: 100/100V		17j	TO-220	BD 901	17j	BD 649, BD 901, BDW 73C, BDX 33C
BDX 53 E		Si-N-Darl+Di	=BDX 53: 140/140V		17j	TO-220	2SD1756	17j	BDX 33E, 2SD1386, 2SD1500
BDX 53 F		Si-N-Darl+Di	=BDX 53: 160/160V		17j	TO-220	2SD1756	17j	2SD1025
BDX 53 H		Si-N-Darl+Di	=BDX 53: 60/60V		17j	TO-220	BD 901	17j	BD 645, BD 897, BDW 73A, BDX 33A
BDX 53 S	Sgs	Si-N-Darl+Di	LF,S, 150/150V, 6/10A, 15W(Tc=25°), 20MHz, hFE>500		2a	TO-39			-
BDX 54	Rca,Tho,++	Si-P-Darl+Di	LF P, 45/45V, 8/12A, 60W, 20MHz, hFE>750	{BDX53	17j	TO-220	BD 902	17j	BD 644, BD 896, BDW 74, BDX 34
BDX 54 A		Si-P-Darl+Di	=BDX 54: 60/60V		17j	TO-220	BD 902	17j	BD 646, BD 898, BDW 74A, BDX 34A
BDX 54 B		Si-P-Darl+Di	=BDX 54: 80/80V		17j	TO-220	BD 902	17j	BD 648, BD 900, BDW 74B, BDX 34B
BDX 54 C		Si-P-Darl+Di	=BDX 54: 100/100V		17j	TO-220	BD 902	17j	BD 650, BD 902, BDW 74C, BDX 34C
BDX 54 E		Si-P-Darl+Di	=BDX 54: 140/140V		17j	TO-220			-
BDX 54 F		Si-P-Darl+Di	=BDX 54: 160/160V		17j	TO-220			-
BDX 54 H		Si-P-Darl+Di	=BDX 54: 60/60V		17j	TO-220	BD 902	17j	BD 646, BD 898, BDW 74A, BDX 34A
BDX 54 S	Sgs	Si-P-Darl+Di	LF,S, 150/150V, 6/10A, 15W(Tc=25°), 20MHz, hFE>500		2a	TO-39			-
BDX 55	Mot	Si-N	LF,S, 100/45V, 7A, 10W(Tc=25°), >4MHz, <500/-ns		2a	TO-39			BU 125, BUY 47…48, BUY 68, BUY 81
BDX 56	Mot	Si-N	=BDX 55: 120/60V		2a	TO-39			BU 125, BUY 47…48, BUY 68, BUY 81
BDX 57	Mot	Si-N	=BDX 55: 140/80V		2a	TO-39			BUY 47…48, BUY 68, BUY 81
BDX 60	Sgs	Si-N	LF,S P, 100/70V, 15A, 150W, >0,8MHz, (=2N3055U)		23a	TO-3	2N3055	23a	BD 317, BDW 51C, 2N3772, 2N5629…31, ++
BDX 61	Sgs	Si-N	=BDX 60: 80/60V, (=2N3055V)		23a	TO-3	2N3055	23a	BD 315, BDW 51B, 2N3772, 2N5629…31, ++
BDX 62	Mot,Phi,Tho	Si-P-Darl+Di	P, 60/60V, 8/12A, 90W, 7MHz, hFE>1000	{BDX63	23a	TO-3	BDW 84 C	18j	BDX 84A, BDX 86A, MJ 900, MJ 2500, ++
BDX 62 A		Si-P-Darl+Di	=BDX 62: 80/80V		23a	TO-3	BDW 84 C	18j	BDX 84B, BDX 86B, MJ 901, MJ 2501, ++
BDX 62 B		Si-P-Darl+Di	=BDX 62: 100/100V		23a	TO-3	BDW 84 C	18j	BDX 84C, BDX 86C, 2SB638…639, ++
BDX 62 C		Si-P-Darl+Di	=BDX 62: 120/120V		23a	TO-3			BDX 64C
BDX 62 L		Si-P-Darl+Di	=BDX 62: 45/45V		23a	TO-3	BDW 84 C	18j	BDX 84A, BDX 86, MJ 900, MJ 2500, ++
BDX 63	Mot,Phi,Tho	Si-N-Darl+Di	P, 80/60V, 8/12A, 90W, 7MHz, hFE>1000	{BDX62	23a	TO-3	BDW 83 C	18j	BDX 83A, BDX 85A, MJ 1000, MJ 3000, ++
BDX 63 A		Si-N-Darl+Di	=BDX 63: 100/80V		23a	TO-3	BDW 83 C	18j	BDX 83B, BDX 85B, MJ 1001, MJ 3001, ++
BDX 63 B		Si-N-Darl+Di	=BDX 63: 120/100V		23a	TO-3			BDX 83C, BDX 85C, 2SD628…629, ++
BDX 63 C		Si-N-Darl+Di	=BDX 63: 140/120V		23a	TO-3			BDX 65C, 2SD922
BDX 63 L		Si-N-Darl+Di	=BDX 63: 60/45V		23a	TO-3	BDW 83 C	18j	BDX 83A, BDX 85, MJ 1000, MJ 3000, ++
BDX 64	Mot,Phi,Tho	Si-P-Darl+Di	P, 60/60V, 12/16A, 117W, 7MHz, hFE>1000	{BDX65	23a	TO-3	BDW 84 C	18j	BDX 66, BDX 88A, MJ 4030, 2N6050
BDX 64 A		Si-P-Darl+Di	=BDX 64: 80/80V		23a	TO-3	BDW 84 C	18j	BDX 66A, BDX 88B, MJ 4031, 2N6051
BDX 64 B		Si-P-Darl+Di	=BDX 64: 100/100V		23a	TO-3	BDW 84 C	18j	BDX 66B, BDX 88C, MJ 4032, 2N6052
BDX 64 C		Si-P-Darl+Di	=BDX 64: 120/120V		23a	TO-3			BDX 66C, MJ 11018
BDX 64 L		Si-P-Darl+Di	=BDX 64: 45/45V		23a	TO-3	BDW 84 C	18j	BDX 66L, BDX 88, MJ 4030, 2N6050
BDX 65	Mot,Phi,Tho	Si-N-Darl+Di	P, 80/60V, 12/16A, 117W, 7MHz, hFE>1000	{BDX64	23a	TO-3	BDW 83 C	18j	BDX 67, BDX 87A, MJ 4033, 2N6057
BDX 65 A		Si-N-Darl+Di	=BDX 65: 100/80V		23a	TO-3	BDW 83 C	18j	BDX 67A, BDX 87B, MJ 4034, 2N6058
BDX 65 B		Si-N-Darl+Di	=BDX 65: 120/100V		23a	TO-3			BDX 67B, BDX 87C, MJ 4035, 2N6059
BDX 65 C		Si-N-Darl+Di	=BDX 65: 140/120V		23a	TO-3			BDX 67C, MJ11017
BDX 65 L		Si-N-Darl+Di	=BDX 65: 60/45V		23a	TO-3	BDW 83 C	18j	BDX 67L, BDX 87, MJ 4033, 2N6057
BDX 66	Mot,Phi,Tho	Si-P-Darl+Di	P, 60/60V, 16/20A, 150W, 7MHz, hFE>1000	{BDX67	23a	TO-3	BDW 84 C	18j	BDW 84A…D, MJ 4030, 2N6285
BDX 66 A		Si-P-Darl+Di	=BDX 66: 80/80V		23a	TO-3	BDW 84 C	18j	BDW 84B…D, MJ 4031, 2N6286
BDX 66 B		Si-P-Darl+Di	=BDX 66: 100/100V		23a	TO-3	BDW 84 C	18j	BDW 84C…D, MJ 4032, 2N6287
BDX 66 C		Si-P-Darl+Di	=BDX 66: 120/120V		23a	TO-3			MJ 11018, MJ 11020
BDX 66 L		Si-P-Darl+Di	=BDX 66: 45/45V		23a	TO-3	BDW 84 C	18j	BDW 84(A…D), MJ 4030, 2N6285
BDX 67	Mot,Phi,Tho	Si-N-Darl+Di	P, 80/60V, 16/20A, 150W, 7MHz, hFE>1000	{BDX66	23a	TO-3	BDW 83 C	18j	BDW 83A…D, MJ 4033, 2N6282
BDX 67 A		Si-N-Darl+Di	=BDX 67: 100/80V		23a	TO-3	BDW 83 C	18j	BDW 83C…D), MJ 4034, 2N6283
BDX 67 B		Si-N-Darl+Di	=BDX 67: 120/100V		23a	TO-3			MJ 4035, 2N6284, MJ 11017, MJ 11019
BDX 67 C		Si-N-Darl+Di	=BDX 67: 140/120V		23a	TO-3			MJ 11017, MJ 11018
BDX 67 L		Si-N-Darl+Di	=BDX 67: 60/45V		23a	TO-3	BDW 83 C	18j	BDW 83(A…D), MJ 4033, 2N6282
BDX 68	Phi	Si-P-Darl+Di	P, 60/60V, 25/40A, 200W, hFE>1000	{BDX69	23a	TO-3			MJ 11011, 2SB694

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BDX 68 A		Si-P-Darl+Di	=BDX 68: 80/80V		23a	TO-3			MJ 11013, 2SB694
BDX 68 B		Si-P-Darl+Di	=BDX 68: 100/100V		23a	TO-3			MJ 11015, 2SB694
BDX 68 C		Si-P-Darl+Di	=BDX 68: 120/120V		23a	TO-3			MJ 11015
BDX 69	Phi	Si-N-Darl+Di	P, 80/60V, 25/40A, 200W, hFE>1000	{BDX68	23a	TO-3			MJ 11012, 2SD730
BDX 69 A		Si-N-Darl+Di	=BDX 69: 100/80V		23a	TO-3			MJ 11014, 2SD730
BDX 69 B		Si-N-Darl+Di	=BDX 69: 120/100V		23a	TO-3			MJ 11016, 2SD730
BDX 69 C		Si-N-Darl+Di	=BDX 69: 140/120V		23a	TO-3			MJ 11016
BDX 70	Rca,Sgs	Si-N	LF,S P, 70/60V, 10A, 75W, >0,8MHz, (=2N6098)		17j	TO-220	BD 809	17j	BD 709, BD 743A, BD 807, BD 909
BDX 71	Rca,Sgs	Si-N	=BDX 70, (=2N6099)		17j	TO-220	BD 809	17j	BD 709, BD 743A, BD 807, BD 909
BDX 72	Rca,Sgs	Si-N	=BDX 70: 80/70, (=2N6100)		17j	TO-220	BD 809	17j	BD 709, BD 743B, BD 809, BD 909
BDX 73	Rca,Sgs	Si-N	=BDX 72, (=2N6101)		17j	TO-220	BD 809	17j	BD 709, BD 743B, BD 809, BD 909
BDX 74	Rca,Sgs	Si-N	=BDX 70: 45/40V, 16A, (=2N6102)		17j	TO-220	BD 809	17j	BD 743, BD 905, BDT 81
BDX 75	Rca,Sgs	Si-N	=BDX 74, (=2N6103)		17j	TO-220	BD 809	17j	BD 743, BD 905, BDT 81
BDX 77	Phi	Si-N	LF,S P, 100/80V, 8/12A, 60W, >7MHz	{BDX78	17j	TO-220	BD 809	17j	BD 543C, BD 711, BD 801, 2SD866
BDX 77 F		Si-N	=BDX 77: Iso, >20W		17c	SOT-186	2SD1411	17c	BDT 95F, 2SD1411, 2SD1588, 2SD1833
BDX 78	Phi	Si-P	LF,S P, 80/80V, 8/12A, 60W, >7MHz	{BDX77	17j	TO-220	BD 810	17j	BD 544B, BD 710, BD 800, BD 810
BDX 78 F		Si-P	=BDX 78: Iso, >20W		17c	SOT-186	2SB1018	17c	BDT 96F, 2SB1018, 2SB1290, 2SA1396
BDX 83	Rca	Si-N-Darl+Di	P, 40/40V, 10/15A, 125W, >20MHz, hFE>1000	{BDX84	23a	TO-3	BDW 83 C	18j	BDW 83, BDX 85, BDX 87, MJ 3000, 2N6057
BDX 83 A		Si-N-Darl+Di	=BDX 83: 60/60V		23a	TO-3	BDW 83 C	18j	BDW83A, BDX85A, BDX87A, MJ3000, 2N6057
BDX 83 B		Si-N-Darl+Di	=BDX 83: 80/80V		23a	TO-3	BDW 83 C	18j	BDW83B, BDX85B, BDX87B, MJ3001, 2N6058
BDX 83 C		Si-N-Darl+Di	=BDX 83: 100/100V		23a	TO-3	BDW 83 C	18j	BDW83C, BDX85C, BDX87C, 2N6059, 2SD628++
BDX 84	Rca	Si-P-Darl+Di	P, 40/40V, 10/15A, 125W, >20MHz, hFE>1000	{BDX83	23a	TO-3	BDW 84 C	18j	BDW 84, BDX 86, BDX 88, MJ 2500, 2N6050
BDX 84 A		Si-P-Darl+Di	=BDX 84: 60/60V		23a	TO-3	BDW 84 C	18j	BDW84A, BDX86A, BDX88A, MJ2500, 2N6050
BDX 84 B		Si-P-Darl+Di	=BDX 84: 80/80V		23a	TO-3	BDW 84 C	18j	BDW84B, BDX86B, BDX88B, MJ2501, 2N6051
BDX 84 C		Si-P-Darl+Di	=BDX 84: 100/100V		23a	TO-3	BDW 84 C	18j	BDW84C, BDX86C, BDX88C, 2N6052, 2SB638++
BDX 85	Sgs	Si-N-Darl+Di	P, 45/45V, 10/15A, 100W, 10MHz, hFE>1000	{BDX86	23a	TO-3	BDW 83 C	18j	BDW 83, BDX 83A, BDX 87, MJ 3000, 2N6057
BDX 85 A		Si-N-Darl+Di	=BDX 85: 60/60V		23a	TO-3	BDW 83 C	18j	BDW83A, BDX83A, BDX87A, MJ3000, 2N6057
BDX 85 B		Si-N-Darl+Di	=BDX 85: 80/80V		23a	TO-3	BDW 83 C	18j	BDW83B, BDX83B, BDX87B, MJ3001, 2N6058
BDX 85 C		Si-N-Darl+Di	=BDX 85: 100/100V		23a	TO-3	BDW 83 C	18j	BDW83C, BDX83C, BDX87C, 2N6059, 2SD628++
BDX 86	Sgs	Si-P-Darl+Di	P, 45/45V, 10/15A, 100W, 10MHz, hFE>1000	{BDX85	23a	TO-3	BDW 84 C	18j	BDW 84, BDX 84A, BDX 88, MJ 2500, 2N6050
BDX 86 A		Si-P-Darl+Di	=BDX 86: 60/60V		23a	TO-3	BDW 84 C	18j	BDW84A, BDX84A, BDX88A, MJ2500, 2N6050
BDX 86 B		Si-P-Darl+Di	=BDX 86: 80/80V		23a	TO-3	BDW 84 C	18j	BDW84B, BDX84B, BDX88B, MJ2501, 2N6051
BDX 86 C		Si-P-Darl+Di	=BDX 86: 100/100V		23a	TO-3	BDW 84 C	18j	BDW84C, BDX84C, BDX88C, 2N6052, 2SB638++
BDX 87	Sgs	Si-N-Darl+Di	P, 45/45V, 12/18A, 120W, 25MHz, hFE>1000	{BDX88	23a	TO-3	BDW 83 C	18j	BDW 83, BDX 67, 2N6057, MJ 4033
BDX 87 A		Si-N-Darl+Di	=BDX 87: 60/60V		23a	TO-3	BDW 83 C	18j	BDW 83A, BDX 67, 2N6057, MJ 4033
BDX 87 B		Si-N-Darl+Di	=BDX 87: 80/80V		23a	TO-3	BDW 83 C	18j	BDW 83B, BDX 67A, 2N6058, MJ 4034
BDX 87 C		Si-N-Darl+Di	=BDX 87: 100/100V		23a	TO-3	BDW 83 C	18j	BDW 83C, BDX 67B, 2N6059, MJ 4035
BDX 88	Sgs	Si-P-Darl+Di	P, 45/45V, 12/18A, 120W, 35MHz, hFE>1000	{BDX87	23a	TO-3	BDW 84 C	18j	BDW 84, BDX 66, 2N6050, MJ 4030
BDX 88 A		Si-P-Darl+Di	=BDX 88: 60/60V		23a	TO-3	BDW 84 C	18j	BDW 84A, BDX 66, 2N6050, MJ 4030
BDX 88 B		Si-P-Darl+Di	=BDX 88: 80/80V		23a	TO-3	BDW 84 C	18j	BDW 84B, BDX 66A, 2N6051, MJ 4031
BDX 88 C		Si-P-Darl+Di	=BDX 88: 100/100V		23a	TO-3	BDW 84 C	18j	BDW 84C, BDX 66B, 2N6052, MJ 4032
BDX 91	Phi	Si-N	LF,S P, 60/60V, 8/12A, 90W, >4MHz, <1/2µs	{BDX92	23a	TO-3	BD 317	23a	BD 245A, BD 311, BDV 91, 2N5873, ++
BDX 92	Phi	Si-P	LF,S P, 60/60V, 8/12A, 90W, >4MHz, <1/2µs	{BDX91	23a	TO-3	BD 318	23a	BD 246A, BD 312, BDV 92, 2N5871
BDX 93	Phi	Si-N	=BDX 91: 80/80V	{BDX94	23a	TO-3	BD 317	23a	BD 245B, BD 313, BDV 93, 2N5874, ++
BDX 94	Phi	Si-P	=BDX 92: 80/80V	{BDX93	23a	TO-3	BD 318	23a	BD 246B, BD 314, BDV 94, 2N5872, ++
BDX 95	Phi	Si-N	=BDX 91: 100/100V	{BDX96	23a	TO-3	BD 317	23a	BD 245C, BDV 95, 2N5632...5633, ++
BDX 96	Phi	Si-P	=BDX 92: 100/100V	{BDX95	23a	TO-3	BD 318	23a	BD 246C, BDV 96, 2N6229...6230, ++
BDY									
BDY 10	Phi	Si-N	LF,S P, 50/40V, 2/4A, 150W, >1MHz		23a	TO-3			BD 311, BDW 21A, 2N3055, 2N4914, ++
BDY 11	Phi	Si-N	=BDY 10: 100/70V		23a	TO-3			BD 317, BDW 21C, 2N3055, 2N5632, ++
BDY 12	Sie	Si-N	LF,S P, 60/40V, 3A, 26W(Tc=45°), 70MHz, <0,3/1,5µs		22a	SOT-9			BDW 25, BDX 25, BDV 10...12, 2SC3252
BDY 13	Sie	Si-N	=BDY 12: 80/60V		22a	SOT-9			BDW 25, BDX 25, BDV 10...12, 2SC3252
BDY 15	Itt	Si-N	LF,S P, 36/36V, 2,5/4A, 11,5W, 100MHz		22a	SOT-9			BDW 25, BDX 25, BDV 10...12, 2SC3252
BDY 16	Itt	Si-N	=BDY 15: 64/64V		22a	SOT-9			BDW 25, BDX 25, BDV 10...12, 2SC3252
BDY 17	Phi	Si-N	LF,S P, 80/60V, 10/25A, 115W, 1MHz		23a	TO-3	2SD1047	18j	BD 745B, BD 313, BDW 21B, 2N3055, ++
BDY 18	Phi	Si-N	=BDY 17: 120/70V		23a	TO-3	2SD1047	18j	BD745D, BDW10, 2N5633, 2SC2706, 2SD1047+
BDY 19	Phi	Si-N	=BDY 17: 150/80V		23a	TO-3	2SD1047	18j	BD745E, BDW12, 2N3442, 2SC2706, 2SD1047+
BDY 20	Phi	Si-N	LF,S P, 100/60V, 15A, 117W, 1MHz, (=2N3055)		23a	TO-3	2N3055	23a	BD 317, BD 745C, BDW 51C, 2N3055, ++
BDY 21	Sie	Si-N	LF,S P, 80/60V, 3A, 25W(Tc=45°), >30MHz, <300/-ns		22a/3Pin	SOT-9a			BDW 25, BDX 25, BDV 10...12, 2SC3252
BDY 22	Sie	Si-N	=BDY 21: 100/80V		22a/3Pin	SOT-9a			BDW 25, BDX 25, BDV 10...12, 2SD772
BDY 23	Tho	Si-N	LF,S P, 60/60V, 6A, 87,5W, >10MHz, <0,5/2µs		23a	TO-3			BD 245A, BD 311, BDW 21A, 2N3055, ++
BDY 24	Tho	Si-N	=BDY 23: 100/90V		23a	TO-3			BD 245C, BD 317, BDW 21C, 2N3055, ++
BDY 25	Tho	Si-N	=BDY 23: 200/140V		23a	TO-3	MJ 15015	23a	BD245F, BDW16, MJ15015, 2SC1585, 2SC2608
BDY 26	Tho	Si-N	=BDY 23: 300/180V		23a	TO-3			BUX 18, BUY 18, BUY 35, BUY 67, ++
BDY 27	Tho	Si-N	=BDY 23: 400/200V		23a	TO-3			BUX 18B, BUY 18S, BUY 67, BUY 77, ++
BDY 28	Tho	Si-N	=BDY 23: 500/250V		23a	TO-3			BUW 34, BUX 15, BUX 45, BUY 69C...70C, ++
BDY 29	Rca	Si-N	LF,S P, 100/75V, 30/30A, 220W, >0,2MHz		23a	TO-3			BDW 30, BDY 57, MJ 802, 2SD797
BDY 34	Aeg	Si-N	LF,S P, 45/40V, 3A, 21W, >80MHz, <0,5/1µs		14h	TO-126	2SD1348	14h	BD 785, MJE 240...242, 2SD1348
BDY 34	Aeg	Si-N	LF,S P, 45/40V, 3A, 13W(Tc=45°), >80MHz, <0,5/1µs		22a	TO-66			BDV 10...12, BDW 25, BDX 25, 2SC3252, ++
BDY 37	Rca	Si-N	LF,S P, 160/140V, 16/30A, 150W, >0,2MHz		23a	TO-3	MJ 15015	23a	BDW 32, BDW 34, BDW 36, BDY 58, 2N3773
BDY 37 A		Si-N	=BDY 37: 250W		23a	TO-3			BDW 32, BDW 34, BDW 36, 2SC2608
BDY 38	Phi	Si-N	LF,S P, 50/40V, 6A, 117W, 1MHz		23a	TO-3	2N3055	23a	BD 311, BD 745A, BDW 21A, 2N3055, ++
BDY 39	Sgs, Sie	Si-N	LF,S P, 100/60V, 15/22A, 117W, 1,1MHz		23a	TO-3	2N3055	23a	BD 317, BD 745C, BDW 51C, 2N3055, ++
BDY 42	Aeg	Si-N	S P, 400/250V, 5/10A, 60W, 12MHz, <55/4000ns		23a	TO-3			BUW 71, BUX 18B, BUY 18S, BUY 67, ++
BDY 43	Aeg	Si-N	=BDY 42: 600/300V		23a	TO-3			BUS 11, BUW 25, BUX 82, BUY 78...79, ++
BDY 44	Aeg	Si-N	=BDY 42: 750/350V		23a	TO-3			BUS 11, BUW 26, BUX 82, BUY 79, ++
BDY 45	Aeg	Si-N	S P, 400/250V, 15/17A, 95W, 13MHz, <0,5/3,5µs		23a	TO-3			BUW 44, BUX 13, BUX 25, BUY 50, ++
BDY 46	Aeg	Si-N	=BDY 45: 600/300V		23a	TO-3			BUS 13, BUW 45...46, BUX 48, 2SD641
BDY 47	Aeg	Si-N	=BDY 45: 750/350V		23a	TO-3			BUS 13, BUW 45...46, BUX 48, 2SC3094
BDY 48/200	Aeg	Si-N	S P, 200V, 3,5A, 100W, 5MHz		23a	TO-3			BUX 16...18, BUY 18, BUY 35, BUY 67, ++
BDY 48/300	Aeg	Si-N	=BDY 48/200: 300V		23a	TO-3			BUX 16A...18A, BUY 18, BUY 35, BUY 67, ++
BDY 48/400	Aeg	Si-N	=BDY 48/200: 400V		23a	TO-3			BUX 16C...18C, BUY 18S, BUY 67, ++
BDY 49	Aeg	Si-N	S P, -/100V, 30A, 150W		23a	TO-3			BDW 30, BDY 29, BDY 57, MJ 802, 2SD797
BDY 53	Tho	Si-N	LF,S P, 100/60V, 12A, 60W, >20MHz		23a	TO-3			BD 317, BD 745C, BDW 51C, 2N3055, ++
BDY 54	Tho	Si-N	=BDY 53: 180/120V		23a	TO-3			BDW 14, BDW 16, BDY 54, BDY 56, ++
BDY 55	Rca,Tho	Si-N	LF,S P, 100/60V, 15A, 115W, >10MHz, <0,5/2µs		23a	TO-3	2N3055	23a	BD 317, BD 745C, BDW 51C, 2N3055, ++
BDY 56	Rca,Tho	Si-N	=BDY 55: 180/120V		23a	TO-3	MJ 15015	23a	BDW 14, BDW 16, BDY 56, 2SC2607, ++
BDY 57(A)	Rca,Tho	Si-N	LF,S P, 120/80V, 25A, 175W, >7MHz, <1/2µs		23a	TO-3			BDW 30, 2N6032, 2N6274...6275
BDY 58	Rca,Tho	Si-N	=BDY 57: 160/125V		23a	TO-3			BDW 32, BDW 34, 2N6276...6277
BDY 58 R	Rca	Si-N	=BDY 57: 250/160V		23a	TO-3			BUV 11...12, BUX 11...12, BUW 58, BUW 73
BDY 60	Phi	Si-N	LF,S P, 120/60V, 5/10A, 15W(Tc=100°), 100MHz		23a	TO-3			BDY 90, 2SC2681, 2SC2706, 2SC2837
BDY 61	Phi	Si-N	=BDY 60: 100/60V		23a	TO-3			BDY 90...91, 2SC2681, 2SC2706, 2SC2837

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BDY 62	Phi	Si-N	=BDY 60: 30V		23a	TO-3			BDY 90...92, 2SC2681, 2SC2706, 2SC2837
BDY 63	Tix	Si-N	S P, 100/80V, 10A, 50W(Tc=100°), >40MHz		49m	TO-61			2N5542
BDY 64	Tix	Si-N	S P, 100/80V, 30A, 100W(Tc=100°), >30MHz		49m	TO-63			2N2824...2825
BDY 65	Tix	Si-N	LF,S P, 150/100V, 1A, 15W(Tc=100°), >30MHz		2a	TO-39			BUY 41
BDY 66	Tix	Si-N	=BDY 65:		49m				2N5002, 2N5504, 2N5284...5285
BDY 67	Tix	Si-P	S P, 100/80V, 5A, 30W(Tc=100°), >30MHz		50g	TO-111			2N5002, 2N5504, 2N5284...5285
BDY 68	Tix	Si-P	=BDY 67:		49m	TO-111a			2N5002, 2N5504, 2N5284...5285
BDY 69	Tix	Si-P	S P, 100/80V, 12A, 50W(Tc=100°), >30MHz		49m	TO-61			2N5542
BDY 70	Tix	Si-P	S P, 100/80V, 2A, 15W(Tc=100°), >30MHz		2a	TO-5			BUY 41
BDY 71	Rca,Tho	Si-N	LF,S P, 90/55V, 4A, 29W, >0,8MHz		22a	TO-66			BD 243B, BD 953, BDY 78, 2N3054, ++
BDY 72	Tho	Si-N	LF,S P, 150/120V, 3A, 25W, >0,8MHz		22a	TO-66			BD241D, BDY79, 2N3441, 2SC2516
BDY 73	Tho	Si-N	LF,S P, 100/60V, 15A, 115W, >0,8MHz		23a	TO-3			BD 317, BD 745C, BDW 51C, 2N3055, ++
BDY 74	Tho	Si-N	=BDY 73: 150/120V		23a	TO-3			BD745E, BDW12, 2N3773, 2SC1584, 2SD1047+
BDY 75	Tho	Si-N	LF,S P, 50/40V, 30A, 150W, >0,8MHz		23a	TO-3			BDY 29, MJ 802, 2N3771, 2SD630
BDY 76	Tho	Si-N	=BDY 75: 100/60V, 20A		23a	TO-3			BD 249C, BDY 29, MJ 802, 2N3772, 2SD797
BDY 77	Tho	Si-N	=BDY 75: 150V, 16A		23a	TO-3	MJ 15015	23a	BD 249D, BDW 32, BDY 58, 2N3773, 2SC2608
BDY 78	Tho	Si-N	LF,S P, 90/55V, 4A, 25W, >0,8MHz		22a	TO-66			BD 243B, BD 953, BDY 71, 2N3054, ++
BDY 79	Tho	Si-N	=BDY 78: 150/120V		22a	TO-66			BD 243D, 2SC2516
BDY 80	Tho,Tos	Si-N	LF,S P, 40/35V, 4A, 36W, 3MHz	{BDY82	17j	TO-220	BD 243 C	17j	BD 243, BD 533, BD 539, BD 947, ++
BDY 81	Tho,Tos	Si-N	=BDY 80: 60/50V	{BDY83	17j	TO-220	BD 243 C	17j	BD 243A, BD 535, BD 539A, BD 949, ++
BDY 82	Tho,Tos	Si-P	LF,S P, 35/35V, 4A, 36W, 3MHz	{BDY80	17j	TO-220	BD 244 C	17j	BD 244, BD 534, BD 540, BD 948, ++
BDY 83	Tho,Tos	Si-P	=BDY 82: 50/50V	{BDY81	17j	TO-220	BD 244 C	17j	BD 244A, BD 536, BD 540A, BD 950, ++
BDY 87	Sie	Si-N-Darl	LF,S P, 20/20V, 8A, 35W(Tc=45°), hFE=2500		(22)	SOT-9/4Pin			-
BDY 88	Sie	Si-N-Darl	=BDY 87: 40/40V		(22)	SOT-9/4Pin			-
BDY 89	Sie	Si-N-Darl	=BDY 87: 60/60V		(22)	SOT-9/4Pin			-
BDY 90	Phi,Sgs,++	Si-N	LF,S P, 120/100V, 10/15A, 60W, 70MHz, <0,35/1,5µs		23a	TO-3			2SC2681, 2SC2706, 2SC2837
BDY 90 A	Phi,Sgs	Si-N	=BDY 90: 12A		23a	TO-3			(2SC2681, 2SC2706, 2SC2837)
BDY 91	Phi,Sgs	Si-N	=BDY 90: 100/80V		23a	TO-3			2SC2681, 2SC2706, 2SC2837
BDY 92	Phi,Sgs	Si-N	=BDY 90: 80/60V		23a	TO-3			2SC2681, 2SC2706, 2SC2837, 2SC3256
BDY 93	Phi,Tho	Si-N	S P, 750/350V, 4/7A, 30W(Tc=75°), 10MHz		23a	TO-3			BUS 11, BUX 46...47, BUX 82...83, ++
BDY 94	Phi,Tho	Si-N	=BDY 93: 750/300V		23a	TO-3			BUS 11, BUX 46...47, BUX 82...83, ++
BDY 95	Phi,Tho	Si-N	=BDY 93: 400/250V		23a	TO-3			BUW 71, BUX 16C, BUX 45, BUY 67, ++
BDY 96	Phi,Tho	Si-N	S P, 750/350V, 10/15A, 40W(Tc=90°), 10MHz		23a	TO-3			BUS 12, BUW 26, BUW 35...36, BUX 80, ++
BDY 97	Phi,Tho	Si-N	=BDY 96: 750/300V		23a	TO-3			BUS 12, BUW 26, BUW 35...36, BUX 80, ++
BDY 98	Phi,Tho	Si-N	=BDY 96: 400/250V		23a	TO-3			BUW 24, BUW 72, BUX 17B, BUX 43, ++
BDY 99	Phi	Si-N	=BDY 96: 750/250V		23a	TO-3			BUS 12, BUW 26, BUW 35...36, BUX 80, ++
BE									
BE		Si-Di	=1SV172 (SMD-Marking)		35	SOT-23			›1SV172
BE		Si-Di	=1SV252 (SMD-Marking)		35 (2mm)	SOT-323			›1SV252
BE		Si-P	=2SB1122 (SMD-Marking)		39	SOT-89			›2SB1122
BE		Si-N	=2SC3440-E (SMD-Marking)		35	SOT-23			›2SC3440
BE		Si-N	=2SC3443-E (SMD-Marking)		39	SOT-89			›2SC3443
BE		Si-N	=BCP 55 (SMD-Marking)		=39°	SOT-223			›BCP 55
BE		Si-P	=BCW 61E(SMD-Marking)		35	SOT-23			›BCW 61E
BE		Si-N	=BCX 55 (SMD-Marking)		39	SOT-89			›BCX 55
BE 565		LIN-IC	=LM 565						›LM 565
BED		Z-Di	=SM 15T 18C (SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BEE		Z-Di	=SM 15T 18CA(SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BEH		Z-Di	=SM 15T 22C (SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BEK		Z-Di	=SM 15T 22CA(SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BEL		Z-Di	=SM 15T 24C (SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BEM		Z-Di	=SM 15T 24CA(SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BEN		Z-Di	=SM 15T 27C (SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BEN 139	Ben	Ge-P	UHF, 700MHz						AF 239(S)
BEP		Z-Di	=SM 15T 27CA(SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BEQ		Z-Di	=SM 15T 30C (SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BER		Z-Di	=SM 15T 30CA(SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BES		Z-Di	=SM 15T 33C (SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BET		Z-Di	=SM 15T 33CA(SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BEU		Z-Di	=SM 15T 36C (SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BEV		Z-Di	=SM 15T 36CA(SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BEW		Z-Di	=SM 15T 39C (SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BEX		Z-Di	=SM 15T 39CA(SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T....
BF									
BF		Si-Di	=1SS268 (SMD-Marking)		35	SOT-23			›1SS268
BF		Si-Di	=1SS312 (SMD-Marking)		35(2mm)	SOT-323			›1SS312
BF		Si-Di	=1SS364 (SMD-Marking)		35(1,6mm)	SS Mini			›1SS364
BF		Si-P	=2SB1123 (SMD-Marking)		39	SOT-89			›2SB1123
BF		Si-N	=2SC3440-F (SMD-Marking)		35	SOT-23			›2SC3440
BF		Si-N	=2SC3443-F (SMD-Marking)		39	SOT-89			›2SC3443
BF(s)		Si-P	=BCW 61FF (SMD-Marking)		35	SOT-23			›BCW 61FF
BF		Si-N	=BCX 55-6 (SMD-Marking)		39	SOT-89			›BCX 55-6
BF 108	Tho	Si-N	Vid, 140/140V, 0,15A, 0,86W, 180MHz		2a	TO-5	BF 259	2a	BF 257...259, BF 657...659, 2N5058...5059
BF 109	Phi	Si-N	Vid, 135V, 0,05A, 0,52W, >80MHz		2a	TO-5	BF 259	2a	BF 257...259, BF 657...659, 2N5058...5059
BF 110	Aeg,Phi,Sie	Si-N	Vid, 160V, 0,04A, 0,75W, 150MHz		2a	TO-39	BF 259	2a	BF 257...259, BF 657...659, 2N5058...5059
BF 111	Sie	Si-N	Vid, 200V, 0,08A, 0,8W, 120MHz		2a	TO-39	BF 259	2a	BF 258...259, BF 658...659, 2N5058...5059
BF 114	Aeg,Phi,Sie	Si-N	Vid, 135V, 0,04A, 1,2W(Tc=60°), >80MHz		2a	TO-5	BF 259	2a	BF 257...259, BF 657...659, 2N5058...5059
BF 115	Phi,Sie,++	Si-N	AM/FM Inp,Mx,Os,IF, 50V, 230MHz, F=4dB(100MHz)		5k	TO-72	BF 255	7d	BF 184...185, BF 240...241, BF 254...255,++
BF 117	Itt	Si-N	Vid, 140/140V, 0,1A, 0,68W, 80MHz		2a	TO-39	BF 259	2a	BF 257...259, BF 657...659, 2N5058...5059
BF 118	Itt	Si-N	Vid, 250V, 0,1A, 0,8W, 110MHz		2a	TO-39	BF 259	2a	BF 258...258, BF 658...659, 2N5058...5059
BF 119	Itt	Si-N	Vid, 160V, 0,1A, 0,8W, 110MHz		2a	TO-39	BF 259	2a	BF 257...259, BF 657...659, 2N5058...5059
BF 120	Itt	Si-N	Vid, TV-HA Os, -/220V, 0,05A, 0,3W		2a	TO-18	BF 420 A	7c	BF 298...299, BF 420, BF 422, 2SC3468,++
BF 121	Itt	Si-N	AM/FM Inp agc, 40/30, 350MHz, F=3,5dB(100MHz)		6k	=SOT-103	BF 198	7d	BF 198, BF 225, BF 310, 2SC1855, 2SC2215
BF 123	Itt	Si-N	TV IF, 40/30V, 550MHz, Gp=44,6dB(35MHz)		6k	=SOT-103	BF 199	7d	BF 199, BF 224, BF 311, 2SC2216, 2SC2717
BF 125	Itt	Si-N	AM/FM Mx,Os,IF, 40/30V, 450MHz, F=3dB(100MHz)		6k	=SOT-103	BF 199	7d	BF 199, BF 224, BF 311, 2SC1393, 2SC1856
BF 127	Itt	Si-N	TV IF, agc, 40/30V, 350MHz, Gp=43,2dB(35MHz)		6k	=SOT-103	BF 198	7d	BF 198, BF 225, BF 310, 2SC1855, 2SC2215
BF 130	Itt	Si-N	Uni, 45/25V, 0,1A, 150MHz		8a	TO-106	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BF 131	Itt	Si-N	=BF 130:		2a	TO-18	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BF 132	Itt	Si-N	Uni, 25/20V, 0,1A, 270MHz		2a	TO-18	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BF 133	Itt	Si-N	=BF 132:		8a	TO-106	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BF 134	Itt	Si-N	FM Mx,Os, 25/12V, 20mA, >600MHz		8a	TO-106	BF 255	7d	BF 240, BF 254, BF 310, BF 314, 2SC829++

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BF 136	Itt	Si-N	FM Inp agc, 30/30V, 20mA, 600MHz		8a	TO-106	BF 255	7d	BF 240, BF 255, BF 495, 2SC829, 2SC2210+
BF 137	Itt	Si-N	Vid, 160/160V, 0,1A, 0,68W, 95MHz		2a	TO-39	BF 259	2a	BF 257…259, BF 657…659, 2N5058…5059
BF 138	Itt	Si-N	FM Inp agc, 30/30V, 20mA, 600MHz		8a	TO-106	BF 198	7d	BF 240, BF 255, BF 310, BF 314, 2SC829++
BF 140	Tho	Si-N	Vid, 135/135V, 0,05A, 0,8W, 100MHz		2a	TO-39	BF 259	2a	BF 257…259, BF 657…659, 2N5058…5059
BF 140 A		Si-N	=BF 140: 150/150V		2a	TO-39	BF 259	2a	BF 257…259, BF 657…659, 2N5058…5059
BF 140 D		Si-N	=BF 140: 180/150V		2a	TO-39	BF 259	2a	BF 258…259, BF 658…659, 2N5058…5059
BF 140 R		Si-N	=BF 140: 0,03A, 0,3W		2a	TO-18	BF 420 A	7c	BF 297…299, BF 420, BF 422, 2SC3468,++
BF 140 S		Si-N	=BF 140: 0,03A		2a	TO-39	BF 259	2a	BF 257…259, BF 657…659, 2N5058…5059
BF 152	Fch,Sgs	Si-N	VHF Mx,Os, 30/12V, 800MHz, Gp=25dB(100MHz)		8a	TO-106	BF 199	7d	BF 224, BF 314, BF 496, BF 502…503, ++
BF 153	Nsc,Sgs	Si-N	AM IF, 30/12V, 400MHz, Gp=44dB(470kHz)		8a	TO-106	BF 199, BF 255	7d	BF 241, BF 254, BF 494, 2SC929, 2SC2210+
BF 154	Sgs	Si-N	Vid Drv, 30/20V, 0,05A, 0,3W, 400MHz		8a	TO-105	BF 959	7d	BF 199, BF 224, BF 311, 2SC1855, 2SC2215
BF 155	Sgs	Si-N	UHF Inp,Mx,Os, 40/40V, 600MHz, Gp=10dB(800MHz)		5g	TO-72	2SC2570A	7f	BF 180…183, BF 689, BF 763, 2N2857, ++
BF 155 R	-	Si-N	Vid, 155V, 0,05A, 0,3W, >40MHz		2a	TO-18	BF 420 A	7c	BF 297…299, BF 420, BF 422, 2SC3468,++
BF 155 S	-	Si-N	=BF 155 R: 0,8W		2a	TO-39	BF 259	2a	BF 257…259, BF 657…659, 2N2058…59
BF 156	Sgs	Si-N	Vid, 120/120V, 0,1A, 0,8W, 60MHz		2a	TO-39	BF 259	2a	BF 257…259, BF 657…659, 2N5058…5059
BF 157	Sgs	Si-N	=BF 156: 150/150V		2a	TO-39	BF 259	2a	BF 257…259, BF 657…659, 2N5058…5059
BF 157 B		Si-N	=BF 156: 175/175V		2a	TO-39	BF 259	2a	BF 257…259, BF 657…659, 2N5058…5059
BF 158	Sgs	Si-N	TV IF, 30/12V, 800MHz, Gp=26dB(40V)		8a	TO-106	BF 199	7d	BF 199, BF 224, BF 311, 2SC2215, 2SC2717
BF 159	Sgs	Si-N	=BF 158: 40/20V		8a	TO-106	BF 199	7d	BF 199, BF 224, BF 311, 2SC2215, 2SC2717
BF 160	Nsc,Sgs	Si-N	AM/FM-ZF, 30/12V, 600MHz, Gp=32dB(10,7MHz)		8a	TO-106	BF 199	7d	BF 241, BF 254, BF 494, 2SC829, 2SC2210+
BF 161	Sgs	Si-N	UHF Inp,Mx,Os, 50/50V, 550MHz, Gp=12dB(800MHz)		5g	TO-72	2SC2570A	7f	BF 180…183, BF 689, BF 763, 2N2857, ++
BF 162	Sgs	Si-N	VHF Inp agc, 40/40V, 600MHz, F=4<5,5dB(200MHz)		8a	TO-106	BF 198	7d	BF 225, BF 314, BF 496, 2SC1393, 2SC1856
BF 163	Sgs	Si-N	TV IF, agc, 40/40V, 600MHz, Gp=30dB(40MHz)		8a	TO-106	BF 198	7d	BF 198, BF 225, BF 310, 2SC1855, 2SC2215
BF 164	Sgs	Si-N	TV IF, agc, 40/40V, 600MHz, Gp=30dB(40MHz)		8a	TO-106	BF 198	7d	BF 198, BF 225, BF 310, 2SC1855, 2SC2215
BF 165	Sgs	Si-N	AM/FM IF, agc, 30/15V, 300MHz, Gp=42dB(1MHz)		8a	TO-105	BF 255	7d	BF 240…241, BF 254…255, BF 494…495,++
BF 166	Sgs	Si-N	VHF Inp,Mx,Os, agc, 40/40V, 500MHz,Gp=24dB(200MHz)		5g	TO-72	BF 199	7d	BF 225, BF 314, BF 496, 2SC1393, 2SC1856
BF 167	EUR	Si-N	TV IF, agc, 40/30V, 350MHz, Gp=42dB(35MHz)		5k	TO-72	BF 198	7d	BF 198, BF 225, BF 310, 2SC1855, 2SC2215
BF 168	Phi	Si-N	TV IF, 50/30V, 550MHz		5k	TO-72	BF 199	7d	BF 199, BF 224, BF 311, 2SC2216, 2SC2717
BF 169	Tho	Si-N	Vid Drv, 50/30V, 0,05/0,1A, 0,3W, >200MHz		2a	TO-18	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BF 169 R		Si-N	=BF 169:		8a	TO-106	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BF 170		Si-N	Vid, 160/160V, 0,05A, 0,8W, 100MHz		2a	TO-5	BF 259	2a	BF 257…259, BF 657…659, 2N5058…5059
BF 173	EUR	Si-N	TV IF, 40/25V, 550MHz, Gp=42,5dB(35MHz)		5k	TO-72	BF 199	7d	BF 199, BF 224, BF 311, 2SC2216, 2SC2717
BF 174	Sgs	Si-N	Vid, 150/150V, 0,1A, 0,8W, 80MHz		2a	TO-39	BF 259	2a	BF 257…259, BF 657…659, 2N5058…5059
BF 175	Sgs	Si-N	TV IF, agc, 40/40, 500MHz, Gp=30dB(40MHz)		5g	TO-72	BF 198	7d	BF 198, BF 225, BF 310, 2SC1855, 2SC2215
BF 176	Sgs	Si-N	TV IF, 40/40V, 450MHz, Gp=30dB(36MHz)		8a	TO-105	BF 199	7d	BF 199, BF 224, BF 311, 2SC2216, 2SC2717
BF 177	EUR	Si-N	Vid, 100/60V, 0,04A, 0,7W, 120MHz		2a	TO-39	BF 259	2a	BF 257…259, BF 657…659, 2N5058…5059
BF 178	EUR	Si-N	Vid, 185/115V, 0,05A, 0,7W, 120MHz		2a	TO-39	BF 259	2a	BF 258…259, BF 658…659, 2N5058…5059
BF 179(A….C)	EUR	Si-N	=BF 178: 185…250V A=185/-V, B=220/-V, C=250/-V		2a	TO-39	BF 259	2a	BF 258…259, BF 658…659, 2N5058…5059
BF 180	Phi,Tho	Si-N	VHF/UHF Inp, 30/20V, 675MHz, Gp=9dB(900MHz)		5g	TO-72	2SC2570A	7f	BF 689, BF 763, 2N918, 2N2857, 2SC3776++
BF 181	Phi,Tho	Si-N	VHF/UHF Mx, 30/20V, 600MHz, Gp=8dB(900MHz)		5g	TO-72	2SC2570A	7f	BF 689, BF 763, 2N918, 2N2857, 2SC3776++
BF 182	Phi,Tho	Si-N	VHF/UHF Mx, 25/20V, 650MHz, Gp=11dB(900MHz)		5g	TO-72	2SC2570A	7f	BF 689, BF 763, 2N918, 2N2857, 2SC3776++
BF 183	Phi,Tho	Si-N	VHF/UHF Os, 25/20V, 800MHz, Gp=13dB(900MHz)		5g	TO-72	2SC2570A	7f	BF 689, BF 763, 2N918, 2N2857, 2SC3776++
BF 184	EUR	Si-N	AM/FM Inp,Mx,Os,IF, 30/20V, 300V, F=3,5dB(1MHz)		5k	TO-72	BF 255	7d	BF 240, BF 254, BF 494, 2SC829, 2SC2210+
BF 185	EUR	Si-N	FM Inp,Mx,Os, 30/20V, 220MHz, F=4dB(100MHz)		5k	TO-72	BF 255	7d	BF 241, BF 255, BF 495, 2SC829, 2SC2210+
BF 186	Phi	Si-N	Vid, 190V, 0,06A, 0,8W, 120MHz		2a	TO-39	BF 259	2a	BF 258…259, BF 658…659, 2N5058…5059
BF 187	Tho	Si-N	HF,IF, 50/30V, 500MHz		2a	TO-18	BF 199	7d	BF 199, BF 224, BF 311, 2SC2215…16,++
BF 188	Tho	Si-N	VHF Mx,Os, 50/50V, 50mA, 600MHz		5g	TO-72	BF 199	7d	BF 224, BF 314, BF 496, 2SC674, 2SC763++
BF 189		Si-N	AM/FM IF, 50/30V, 270MHz, Gp=42dB(35MHz)		5k	TO-72	BF 255	7d	BF 240, BF 254, BF 494, 2SC829, 2SC2210+
BF 194	Aeg,Phi,Tho	Si-N	AM/FM Inp,Mx,Os,IF, 260MHz, F=1,2dB(1MHz)		11d	SOT-25	BF 255	7d	BF 240, BF 254, BF 494, 2SC829, 2SC2210+
BF 195	Aeg,Phi,Tho	Si-N	FM Inp,Mx,Os, 30/20V, 200MHz, F=4dB(100MHz)		11d	SOT-25	BF 255	7d	BF 241, BF 255, BF 495, 2SC829, 2SC2210+
BF 196	Aeg,Phi,Tho	Si-N	=BF 198:		11d, 12d	SOT-25/-33	›BF 198		›BF 198
BF 197	Aeg,Phi,Tho	Si-N	=BF 199:		11d, 12d	SOT-25/-33	›BF 199		›BF 199
BF 198	EUR	Si-N	TV IF, agc, 40/30V, 400MHz, Gp=42dB(35MHz)		7d	TO-92	BF 198	7d	BF 225, BF 310, 2SC1855, 2SC2215,++
BF 199	EUR	Si-N	TV IF, 40/25V, 550MHz, Gp=43dB(35MHz)		7d	TO-92	BF 199	7d	BF 224, BF 311, 2SC2216, 2SC2717,++
BF 200	Mot,Phi,Tho	Si-N	FM/VHF Inp, 30/20V, 650MHz, F=2,7dB(200MHz)		5g	TO-72	2SC2570A	7f	BF 225, BF 314, BF 496, 2SC1393, 2SC1856
BF 202	Aeg	Si-N	VHF/UHF, 30V, 650MHz		2a	TO-18			BF 689, BF 763, 2N918, 2N2857, 2SC3776++
BF 203	Aeg	Si-N	VHF/UHF, 30V, 900MHz		2a	TO-18			BF 689, BF 763, 2N918, 2N2857, 2SC3776++
BF 206	Tho	Si-N	VHF, 30/20V, 500MHz		5g	TO-72	BF 198	7d	BF 225, BF 314, BF 496, 2SC1393, 2SC1856
BF 207	Tho	Si-N	VHF,IF, 40/30V, 400MHz		5k	TO-72	BF 198	7d	BF 198, BF 225, BF 310, 2SC1855, 2SC2215
BF 208	Tho	Si-N	VHF,IF, 40/25V, 600MHz		5k	TO-72	BF 199	7d	BF 199, BF 224, BF 311, 2SC1855, 2SC2215
BF 209	Tho	Si-N	VHF, 30/20V, 500MHz, F<5dB(200MHz)		5g	TO-72	BF 198	7d	BF 225, BF 314, BF 496, 2SC1393, 2SC1856
BF 212	Tho	Si-N	UHF Os, 30/20V, 700MHz		5g	TO-72	2SC2570A	7f	BF 180…183, BF 689, BF 763, 2N2857, ++
BF 213	Tho	Si-N	UHF Mx, 30/20V, 600MHz		5g	TO-72	2SC2570A	7f	BF 180…182, BF 689, BF 763, 2N2857, ++
BF 214	Tho	Si-N	AM/FM Inp,Mx,Os,IF, 30/30V, 250MHz		5k	TO-72	BF 255	7d	BF 240, BF 254, BF 494, 2SC829, 2SC2210+
BF 215	Tho	Si-N	FM Inp,Mx,Os, 30/30V, 250MHz		5k	TO-72	BF 255	7d	BF 241, BF 255, BF 495, 2SC829, 2SC2210+
BF 216	Aei	Si-N	FM Inp, 40/34V, 220MHz		7c	TO-98	BF 255	7d	BF 241, BF 255, BF 495, 2SC829, 2SC2210+
BF 217	Aei	Si-N	FM Mx, 40/35V, 240MHz		7c	TO-98	BF 255	7d	BF 241, BF 255, BF 495, 2SC829, 2SC2210+
BF 218	Aei	Si-N	AM/FM IF, 40/35V, 220MHz		7c	TO-98	BF 255	7d	BF 240, BF 254, BF 494, 2SC829, 2SC2210+
BF 219	Aei	Si-N	AM Inp,Mx,Os, 40/35V, 260MHz		7c	TO-98	BF 255	7d	BF 240, BF 254, BF 494, 2SC829, 2SC2210+
BF 220	Aei	Si-N	AM/FM Os, 40/35V, 260MHz		7c	TO-98	BF 255	7d	BF 240, BF 254, BF 494, 2SC829, 2SC2210+
BF 221 [Riz]	Riz	Si-N	HF,IF, 30/20V, 135MHz		2a	TO-18L	BF 255	7d	BF 240…241, BF 254…255, BF 494…495,++
BF 222 [Riz]	Riz	Si-N	HF,IF, 30/20V, 135MHz		2a	TO-18L	BF 255	7d	BF 240…241, BF 254…255, BF 494…495,++
BF 222 [SGS]	Sgs	Si-N	FM Inp agc, 50/50V, 400MHz, F<5dB(100MHz)		5g	TO-72	BF 255	7d	BF 225, BF 314, BF 496, 2SC1393, 2SC1856
BF 223 [AEG]	Aeg	Si-N	TV IF, 35/25V, 40mA, 750MHz		11d		BF 199	7d	BF 199, BF 224, BF 311, 2SC2216, 2SC2717
BF 223 [Riz]	Riz	Si-N	HF,IF, 30/20V, 135MHz		2a	TO-18L	BF 255	7d	BF 240…241, BF 254…255, BF 494…495,++
BF 224	Tix	Si-N	TV IF, VHF Mx,Os, 45/30V, 700MHz, F=4dB(200MHz)		7d	SOT-30	BF 199	7d	BF 199, BF 311, 2SC1393, 2SC1855…56,++
BF 225	Tix	Si-N	TV IF, agc, VHF Inp, 700MHz, Gp=44dB(35MHz)		7d	SOT-30	BF 198	7d	BF 198, BF 310, 2SC1393, 2SC1855…56,++
BF 226	Tho	Si-N	FM Mx,Os, 30/30V, 250MHz		5k	TO-72	BF 255	7d	BF 240…241, BF 254…255, BF 494…495,++
BF 227	Aeg	Si-N	Min, TV IF, 40/25V, 600MHz		36d	(TOM-23)			(BF 199, BF 224, BF 311, 2SC1855…56,++)[6]
BF 228	Aeg	Si-N	Min, Nixie Drv, 100/80V, 50mA, 0,05W, >50MHz		36c	(TOM-23)			BF 622, (BF 297…299, BF 422, BF 420)[6]
BF 229	Aeg	Si-N	Min, AM Inp,Mx,Os, AM/FM IF, 30/20V, 260MHz		36d	(TOM-23)			(BF 240, BF 254, BF 494, 2SC829, ++)[6]
BF 230	Aeg	Si-N	Min, FM Inp,Mx,Os, 30/20V, 200MHz, F=4dB(100MHz)		36d	(TOM-23)			(BF 241, BF 255, BF 495, 2SC829, ++)[6]
BF 231 [Riz]	Riz	Si-N	AM/FM/VHF, 30/12V, 800MHz		2a	TO-18	BF 199	7d	BF 199, BF 224, BF 311, 2SC1393, 2SC1856
BF 232 [Riz]	Riz -	Si-N	AM/FM/VHF, 30/12V, 300MHz		2a	TO-18	BF 199	7d	BF 199, BF 224, BF 311, 2SC1393, 2SC1856
BF 232 [Siemens]	Sie	Si-N	TV IF, 48/25V, 600MHz		5k	TO-72	BF 199	7d	BF 199, BF 224, BF 311, 2SC2215…16,++
BF 233 [CSF,SGS]	Nsc,Sgs	Si-N	AM/FM IF, 30/30V, 500MHz, Gp=40dB(470kHz)		8d	TO-106	BF 255	7d	BF 240, BF 254, BF 494, 2SC829, 2SC2210+
BF 233 [Riz]	Riz	Si-N	AM/FM/VHF, 30/12V, 800MHz		2a	TO-18	BF 199	7d	BF 199, BF 224, BF 311, 2SC1393, 2SC1856
BF 234 [CSF,SGS]	Sgs	Si-N	AM Inp,Mx,Os,IF, 30/30V, 500MHz, Gp=40dB(470kHz)		8d	TO-106	BF 255	7d	BF 240…241, BF 254…255, BF 494…495,++
BF 234 [Riz]	Riz	Si-N	AM/FM/VHF, -/13V, 300MHz		2a	TO-18	BF 199	7d	BF 199, BF 224, BF 311, 2SC1393, 2SC1856
BF 235 [CSF,SGS]	Sgs	Si-N	FM Inp,Mx, 30/30V, 500MHz, F=3,5dB(100MHz)		8d	TO-106	BF 255	7d	BF 241, BF 255, BF 495, 2SC829, 2SC2210+
BF 235 [Riz]	Riz	Si-N	AM/FM/VHF, 30/12V, 400MHz		2a	TO-18	BF 199	7d	BF 199, BF 224, BF 311, 2SC1393, 2SC1856
BF 236	Tho	Si-N	FM/VHF Os, 30/30V, 250MHz		8d	TO-106	BF 255	7d	BF 240…241, BF 254…255, BF 494…495,++

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BF 237	Tix	Si-N	FM Inp,Mx,Os,IF, 45/30V,30mA		7d	SOT-30	BF 255	7d	BF 241, BF 255, BF 495, 2SC829, 2SC2210+
BF 238	Tix	Si-N	AM Inp,Mx,Os,IF, 45/30V, 30mA		7d	SOT-30	BF 255	7d	BF 240, BF 254, BF 494, 2SC829, 2SC2210+
BF 240	EUR	Si-N	AM/FM IF, agc, 40/40V, 400MHz, F=1,6dB(100MHz)		7d	TO-92	BF 255	7d	BF 254...255, BF 494...495, 2SC2210,++
BF 240 B	Pih	Si-N	=BF 240:		10d		›BF 240		›BF 240
BF 240 [Riz]	Riz	Si-N	Uni, 15/15V, 0,1A, 0,3W, >90MHz		2a	TO-18	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BF 241	EUR	Si-N	AM/FM IF, 40/40V, 400MHz, F=1,6dB(100MHz)		7d	TO-92	BF 255	7d	BF 254...255, BF 494...495, 2SC2210,++
BF 241 [Riz]	Riz	Si-N	Uni, 30/30V, 0,1A, 0,3W, 125MHz		2a	TO-18	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BF 241 A [Riz]		Si-N	=BF 241[Riz]: 60/60V		2a	TO-18	BC 546	7a	BC 167, BC 182, BC 237, BC 546, 2SD767++
BF 241 C,D [Piher]	Pih	Si-N	=BF 241:		10d		›BF 241		›BF 241
BF 242 [Riz]	Riz	Si-N	Uni, 30/30V, 0,1A, 0,3W, 140MHz		2a	TO-18	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BF 242 A [Riz]		Si-N	=BF 242[Riz]: 60/60V		2a	TO-18	BC 546	7a	BC 167, BC 182, BC 237, BC 546, 2SD767++
BF 243 [Riz]	Riz	Si-N	Uni, 30/30V, 0,1A, 0,3W, 170MHz		2a	TO-18	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BF 243 [Texas]	Tix	Si-P	AM Inp,Mx,Os,IF, 35/32V, >80MHz		7d	SOT-30	BF 324	7a	BF 324, BF 440...441, BF 450...451, ++
BF 244 [Riz]	Riz	Si-N	Uni, 30/30V, 0,1A, 0,3W, 170MHz		2a	TO-18	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BF 244	Phi,Sie,++	N-FET	LF,HF...VHF, 30V, Idss=2...25mA, Up=0,5...8V, 700MHz		7e	TO-92	BF 245	7f	BFW 61, BFS 72, 2N3819, 2N3823, ++
BF 245	Phi,Sie,++	N-FET	=BF 244:		7f	SOT-30	›BF 244		›BF 244
BF 246	Phi,Sie,++	N-FET	FM/VHF, 25V, Idss=10...300mA, Up=0,6...14,5V, 450MHz		7e	TO-92			-
BF 247	Phi,Sie,++	N-FET	=BF 246:		7f	SOT-30			-
BF 248	Tix	Si-N	LF Drv, 30/25V, 0,6A, 0,4W, 250MHz	{BF249	2a	TO-18	BC 337	7a	BC 337...338, BC 635, BC 637, 2SC3377,++
BF 249	Tix	Si-P	LF Drv, 30/25V, 0,6A, 0,4W, 250MHz	{BF248	2a	TO-18	BC 327	7a	BC 327...328, BC 636, BC 638, 2SA1515,++
BF 250	Tix	Si-N	LF Drv, 15/15V, 0,6A, 0,4W, 20MHz		2a	TO-18	BC 337	7a	BC 337-338, BC 635, BC 637, 2SC3377,++
BF 251	Sgs	Si-N	TV IF, agc, 30/30V, 600MHz, Gp=33dB(36MHz)		5k	TO-72	BF 198	7d	BF 167, BF 198, BF 225, BF 310, 2SC2215+
BF 252	Sgs	Si-N	TV IF, 40/30V, 400MHz, Gp=19dB(100MHz)		5k	TO-72	BF 198	7d	BF 167, BF 198, BF 225, BF 310, 2SC2215+
BF 253	Tho	Si-N	AM Inp,Mx,Os, 30/30V, >150MHz, F=4dB(200kHz)		7d	SOT-30	BF 255	7d	BF 240, BF 254, BF 494, 2SC829, 2SC2210+
BF 254	EUR	Si-N	AM Inp,Mx,Os,IF, 30/20V, 260MHz, 1,2dB(1MHz)		7d	TO-92	BF 255	7d	BF 240, BF 241, BF 494, 2SC829, 2SC2210+
BF 255	EUR	Si-N	FM Inp,Mx,Os, 30/20V, 200MHz, F=4dB(100MHz)		7d	TO-92	BF 255	7d	BF 240, BF 241, BF 495, 2SC829, 2SC2210+
BF 255 [Riz]	Riz	Si-N	HF,IF, 40V, 600MHz		5k	TO-72	BF 199	7d	BF 199, BF 224, BF 311, 2SC1393, 2SC1856
BF 256	Mot,Phi,++	N-FET	VHF/UHF, 30V, Idss=3...18mA, Up=0,5...7,5V, 1GHz		7f	SOT-30	(BF 245)	7f	2N5397...5398, 2N5486
BF 256 L	Tix	N-FET	=BF 256:		7e	TO-92	›BF 256		›BF 256
BF 257	EUR	Si-N	Vid, 160/160V, 0,1/0,2A, 0,8W, 90MHz		2a	TO-39	BF 259	2a	BF 657...659, 2N5058...5059
BF 257 A	Tix	Si-N	=BF 257: 180/180V		2a	TO-39			BF 658...659, 2N5058...5059
BF 257 B	Tix	Si-N	=BF 257: 220/220V		2a	TO-39			BF 658...659, 2N5058...5059
BF 257 C	Tix	Si-N	=BF 257: 220/220V		2a	TO-39			BF 658...659, 2N5058...5059
BF 257 D	Tix	Si-N	=BF 257: 160/160V		2a	TO-39			BF 657...659, 2N5058...5059
BF 257 G	Tix	Si-N	=BF 257: 200/170V		2a	TO-39			BF 658...659, 2N5058...5059
BF 257 N	Tix	Si-N	=BF 257: 180/180V		2a	TO-39			BF 658...659, 2N5058...5059
BF 257 S	Tix	Si-N	=BF 257: 140/140V		2a	TO-39			BF 657...659, 2N5058...5059
BF 258	EUR	Si-N	=BF 257: 250/250V		2a	TO-39	BF 259	2a	BF 658...659, 2N5058...5059
BF 258 A	Tix	Si-N	=BF 257: 280/280V		2a	TO-39			BF 659, BFS 89, 2N5058
BF 259(A,G)	EUR	Si-N	=BF 257: 300/300V		2a	TO-39	BF 259	2a	BF 659, BFS 89, 2N5058
BF 260	Sgs	Si-N	VHF Inp agc, 45/30V, 800MHz, F<4dB(200MHz)		5k	TO-72	BF 198	7d	BF 225, BF 314, BF 496, 2SC1393, 2SC1856
BF 261 [ATES,CSF]	Sgs	Si-N	TV IF, agc, 40/30V, 730MHz, Gp=26dB(35MHz)		5k	TO-72	BF 198	7d	BF 198, BF 225, BF 310, 2SC1855, 2SC2215
BF 261 [Riz]	Riz	Si-N	AM/FM/VHF, 50/50V		5g	TO-72	BF 199	7d	BF 199, BF 225, BF 311, 2SC1393, 2SC1856
BF 262	Phi	Si-N	UHF Inp, 30/20V, 650MHz, F=5dB(800MHz)		24a	SOT-37	2SC2466	25p	BF 362, 2SC2464...66, 2SC2360, 2SC2726,++
BF 263	Phi	Si-N	UHF Mx, 30/20V, >525MHz		24a	SOT-37	2SC2466	25p	BF 363, 2SC2464...66, 2SC2360, 2SC2726,++
BF 264	Phi,Tho	Si-N	UHF Mx, 30/20V, >400MHz, F=2,3dB(200MHz)		24a	SOT-37	2SC2466	25p	BF 363, 2SC2464...66, 2SC2360, 2SC2726,++
BF 265	Riz	Si-N	UHF Inp,Mx,Os, 40/40V, 600MHz		5k	TO-72	2SC2570A	7f	BF 180...183, BF 689, BF 763, 2N2857, ++
BF 266	Riz	Si-N	VHF Inp agc, 40/40, 400MHz		5g	TO-72	2SC2570A	7f	BF 225, BF 314, BF 496, 2SC1393, 2SC1856
BF 267	Riz	Si-N	TV IF, agc, 40/30, 350MHz		5k	TO-72	BF 198	7d	BF 198, BF 225, BF 310, 2SC1855, 2SC2215
BF 268	Sgs	Si-N	VHF/UHF, 30/30, 600MHz						BF 180...183, BF 689, BF 763, 2N2857, ++
BF 269	Sgs	Si-N							-
BF 270	Sgs	Si-N	TV IF, agc, 30/25V, 600MHz, Gp=26dB(36MHz)		5k	TO-72	BF 198	7d	BF 198, BF 225, BF 310, 2SC1393, 2SC2215
BF 271	Sgs	Si-N	TV IF, 30/30V, 900MHz, Gp=27dB(36MHz)		5k	TO-72	BF 199	7d	BF 199, BF 224, BF 311, 2SC2216, 2SC2717
BF 272(A,S)	Sgs	Si-P	UHF Inp agc, 40/35V, 850MHz, F<6dB(800MHz) A: F<4,5dB(800MHz), S: F<3,9dB(800MHz)		5g	TO-72			BF 316, BF 516, BF 606, BFR 38
BF 272 [Riz]	Riz	Si-N	TV IF, 30V, 775MHz		5k	TO-72	BF 198	7d	BF 198, BF 225, BF 310, 2SC2215...16,++
BF 273 [Riz]	Riz	Si-N	TV IF, 40/25V, 550MHz		5k	TO-72	BF 199	7d	BF 199, BF 224, BF 311, 2SC2215...16,++
BF 273 [SGS]	Sgs	Si-N	AM/FM Mx,Os,IF, 25/25V, 700MHz, F=2dB(100MHz)		8d	TO-106	BF 255	7d	BF 240...241, BF 254...255, BF 494...495,++
BF 274 [SGS]	Sgs	Si-N	AM/FM IF, agc, 25/25V, 700MHz		8d	TO-106	BF 255	7d	BF 240...241, BF 254...255, BF 494...495,++
BF 275	Riz	Si-N	VHF, 40/40V, 500MHz		5g	TO-72	2SC2570A	7f	BF 225, BF 314, BF 496, 2SC1855...56, ++
BF 277	Tho	Si-N	HF,IF, 40V, 350MHz		6k	=SOT-103			BF 225, BF 314, BF 496, 2SC2454...55, ++
BF 278	Tho	Si-N	HF,IF, 40V, 550MHz		6k	=SOT-103			BF 225, BF 314, BF 496, 2SC2454...55, ++
BF 279	Tho	Si-N	HF,IF, 30V, 500MHz		6k	=SOT-103			BF 225, BF 314, BF 496, 2SC2454...55, ++
BF 280	Tho	Si-N	HF,IF, 30V, 500MHz		6k	=SOT-103			BF 225, BF 314, BF 496, 2SC2455...56, ++
BF 281	Tho	Si-N	HF,IF, 30V, 700MHz		6k	=SOT-103			BF 225, BF 314, BF 496, 2SC2454...55, ++
BF 282	Tho	Si-N	HF,IF, 30V, 600MHz		6k	=SOT-103			BF 225, BF 314, BF 496, 2SC2454...55, ++
BF 283	Tho	Si-N	HF,IF, 30V, 250MHz		6k	=SOT-103			BF 225, BF 314, BF 496, 2SC2454...55, ++
BF 284	Tho	Si-N	HF,IF, 30V, 250MHz		6k	=SOT-103			BF 225, BF 314, BF 496, 2SC2454...55, ++
BF 285	Tho	Si-N	HF,IF, 30V, 250MHz		6k	=SOT-103			BF 225, BF 314, BF 496, 2SC2454...55, ++
BF 286	Tho	Si-N	HF,IF, 30V, 250MHz		6k	=SOT-103			BF 225, BF 314, BF 496, 2SC2454...55, ++
BF 287	Sgs	Si-N	AM Mx,Os,IF, 40/40V, 600MHz, Gp=45dB(470kHz)		5k	TO-72	BF 255	7d	BF 241, BF 255, BF 495, 2SC829, 2SC2210+
BF 288	Sgs	Si-N	AM/FM IF, agc, 40/40V, 500MHz, Gp=22dB(10,7MHz)		5k	TO-72	BF 255	7d	BF 240, BF 254, BF 494, 2SC829, 2SC2210+
BF 290 [SGS]	Sgs	Si-N	VHF Mx,Os, 40/40V, 1000MHz		5k	TO-72	2SC2570A	7f	BF 180...183, BF 689, BF 763, 2N2857, ++
BF 290 [Riz]	Riz	Si-N	Vid, 120/120V, 0,03A, 0,8W, 80MHz		2a	TO-5	BF 259	2a	BF 257...259, BF 657...659, 2N5058...5059
BF 291 [Riz]	Riz	Si-N	Vid, 150/150V, 0,03A, 0,8W, 80MHz		2a	TO-5	BF 259	2a	BF 257...259, BF 657...659, 2N5058...5059
BF 291 A [Riz]		Si-N	=BF 291[Riz]: 160/160V		2a	TO-5	BF 259	2a	BF 257...259, BF 657...659, 2N5058...5059
BF 291(A,B) [SGS]	Sgs	Si-N	Uni, 50/40V, 0,1A, 0,36W, 260MHz		2a	TO-18	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BF 292 A	Sgs	Si-N	Vid, 150/150V, 0,3A, 0,8W, 66MHz		2a	TO-39	BF 259	2a	BF 257...259, BFR 57...59, 2N5058...5059
BF 292 B		Si-N	=BF 292A: 190/190V		2a	TO-39	BF 259	2a	BF 258...259, BFR 58...59, 2N5058...5059
BF 292 C		Si-N	=BF 292A: 220/220V		2a	TO-39	BF 259	2a	BF 258...259, BFR 58...59, 2N5058...5059
BF 293(A,D)	Sgs	Si-N	Uni, 50/45V, 0,1A, 0,36W, 250...380MHz		2a	TO-18	BC 546	7a	BC 167, BC 182, BC 237, BC 547, 2SD767++
BF 294	Sgs	Si-N	Vid, 160/160V, 0,1A, 0,8W, >40MHz		2a	TO-39	BF 259	2a	BF 257...259, BF 657...659, 2N5058...5059
BF 297	Tik	Si-N	Vid, 160/160V, 0,1A, 0,625W, 95MHz		7a	SOT-30	BF 420 A	7c	BF 420, BF 422, BFR 87...89, BFT 57...59++
BF 297 P	Tho	Si-N	=BF 297: 1W		30a	TO-237			2SC1758,(BF457...459, 2SC3805, 2SC4019++)[5]
BF 297 P2	Tho	Si-N	=BF 297: 1W		30b	TO-237			BF 457...459, BF 615, BF 857...859, ++
BF 298	Tix	Si-N	=BF 297: 250V		7a	SOT-30	BF 420 A	7c	BF 420, BF 422, BFR 88...89, BFT 58...59++
BF 298 P	Tho	Si-N	=BF 298: 1W		30a	TO-237			2SC1758,(BF458...459, 2SC3805, 2SC4019++)[5]
BF 298 P2	Tho	Si-N	=BF 298: 1W		30b	TO-237			BF 458...459, BF 615, BF 858...859, ++
BF 299	Tix	Si-N	=BF 297: 300V		7a	SOT-30	BF 420 A	7c	BF 420, BFR 89, BFT 59
BF 299 P	Tho	Si-N	=BF 299: 1W		30a	TO-237			2SC1758,(BF459, BF859, 2SC2805, 2SC4019)[5]
BF 299 P2	Tho	Si-N	=BF 299: 1W		30b	TO-237			BF 459, BF 617, BF 859, ++
BF 302	Sgs	Si-N	FM IF, 40/30V, 650MHz, F=4dB(100MHz)		5k	TO-72	BF 199	7d	BF 240...241, BF 254...255, BF 494...495,++
BF 303	Sgs	Si-N	AM Inp,Mx,Os,IF, 40/40V, 500MHz, F=3,5dB(1MHz)		5k	TO-72	BF 199	7d	BF 240...241, BF 254...255, BF 494...495,++

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
BF 304	Sgs	Si-N	TV IF, 40/30V, 500MHz, F=3.5dB(1MHz)		5k	TO-72	BF 199	7d	BF 199, BF 224, BF 311, 2SC2215...16,++
BF 305	Sgs	Si-N	Vid, 185/150V, 0,1/0,15A, 0,6W, 100MHz		2a	TO-39	BF 259	2a	BF 258...259, BF 658...659, 2N5058...5059
BF 306	Sgs	Si-N	TV IF, 40/25V, 1000MHz		5k	TO-72	BF 199	7d	BF 199, BF 224, BF 311, 2SC2215...16,++
BF 307		Si-N	TV IF		5k	TO-72	BF 199	7d	BF 199, BF 224, BF 311, 2SC2215...16,++
BF 308	Sgs	Si-N	TV IF, 40/35V, >800MHz		5k	TO-72	BF 199	7d	BF 199, BF 224, BF 311, 2SC2215...16,++
BF 309	Sgs	Si-N	TV IF, 40/35V, >800MHz		5k	TO-72	BF 198	7d	BF 198, BF 225, BF 310, 2SC2215...16,++
BF 310	Aeg,Sie	Si-N	FM Inp, TV IF, 30/30V, 580MHz		7a	TO-92	BF 198	7d	BF 198, BF 225, BF 314, 2SC1855...56,++
BF 311	Aeg,Phi	Si-N	TV IF, 35/25V, 750MHz		7d	TO-92	BF 199	7d	BF 199, BF 224, 2SC2215...16, 2SC2717,++
BF 314	Aeg,Sie	Si-N	FM/VHF Inp, 30/30V, 450MHz, F=2dB(100MHz)		7a	TO-92	2SC2570A	7f	BF 225, BF 496, 2SC1393, 2SC1856,++
BF 315	Sgs	Si-P	AM/FM, 20/20V, 500MHz, F=3.5dB(1MHz)		2a	TO-18	BF 324	7a	BF 324, BF 440...441, BF 450...451, ++
BF 316(A)	Sgs	Si-P	UHF Mx,Os, 40/35V, 550...600MHz, F=5dB(800MHz) BF316: 550MHz, Gp=11dB, A: 600MHz, Gp=12dB(800MHz)		5g	TO-72			BF 272, BF 516, BF 606, BFR 38
BF 317	Sgs	Si-P	=BF 315:		8a	TO-106	›BF 315		›BF 315
BF 320	Tix	P-FET	LF,HF, 15V, Idss=0,3...15mA, Up=0,3...7,9V		7e	TO-92			2N3820. 2N3909, 2N5800, 2N5462, ++
BF 321(A....F)	Tho	Si-N	Uni, 30/20V, 0,03A, 0,3W		8a	TO-106	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BF 322	Tix	Si-N	LF,S, 30/25V, 0,6A, 0,4W, 250MHz	{BF323	2a	TO-39	BC 141	2a	BC 140...141, BC 337...338, BC 635, ++
BF 323	Tix	Si-P	LF,S, 30/25V, 0,6A, 0,4W, 250MHz	{BF322	2a	TO-39	BC 161	2a	BC 160...161, BC 327...328, BC 636, ++
BF 324	Phi,Sie,++	Si-P	FM/VHF Inp, 30/30V, 450MHz, F=3dB(100MHz)		7a	TO-92	BF 324	7a	BF 414, BF 506, BF 914, BF 936, BF 939
BF 325	Tix	Si-N	TV IF, 50/40V, 700MHz		7a	SOT-30	BF 198	7d	BF 198, BF 225, BF 310, 2SC2215...16,++
BF 327	Phi	MOS-N-FET-d	Dual-Gate, VHF, 20V, Idss=20...55mA, Up=1,5...3,8V		25g	SOT-103			-
BF 329	Sgs	Si-N	TV IF, agc, 40/30V, 730MHz, Gp=26dB(36,6MHz)		11d	SOT-25	BF 198	7d	BF 198, BF 225, BF 310, 2SC1855, 2SC2215
BF 330	Sgs	Si-N	TV IF, 40/25V, 1000MHz, Gp=26dB(35MHz)		11d	SOT-25	BF 199	7d	BF 199, BF 224, BF 311, 2SC2215...16,++
BF 332	Sgs	Si-N	AM/FM Mx,Os,IF, 30/20V, 600MHz, F=4dB(100MHz)		11d	SOT-25	BF 255	7d	BF 240...241, BF 254...255, BF 494...495,++
BF 333	Sgs	Si-N	AM/FM Mx,Os,IF, 30/20V, 400MHz, F=4dB(100MHz)		11d	SOT-25	BF 255	7d	BF 240...241, BF 254...255, BF 494...495,++
BF 334	Phi	Si-N	AM Inp,Mx,Os,IF, 40/30V, 430MHz, F=1,5dB(200kHz)		11d	SOT-25	BF 255	7d	BF 240...241, BF 254...255, BF 494...495,++
BF 335	Phi	Si-N	FM Inp,Mx,Os,IF, 370MHz, F=2dB(200kHz)		11d	SOT-25	BF 255	7d	BF 240...241, BF 254...255, BF 494...495,++
BF 336	Mot,Phi,Tho	Si-N	Vid, 185/180V, 0,1/0,2A, 0,8W, 130MHz		2a	TO-39	BF 259	2a	BF 258...259, BF 658...659, 2N5058...5059
BF 336 D	Tix	Si-N	=BF 336: 0,5A, 0,5W		2a	TO-5			2SD413, 2SD576, 2SD624
BF 337	Mot,Phi,Tho	Si-N	=BF 336: 250V		2a	TO-39	BF 259	2a	BF 258...259, BF 658...259, 2N5058...5059
BF 337 D	Tix	Si-N	=BF 337: 0,5A, 0,5W		2a	TO-5			2SD576, 2SD593
BF 338	Mot,Phi,Tho	Si-N	=BF 336: 300V		2a	TO-39	BF 259	2a	BF 259, BF 659, BFS 89, 2N5058
BF 338 D	Tix	Si-N	=BF 338: 0,5A, 0,5W		2a	TO-5			2SD593
BF 339	Tix	Si-P	VHF Inp,Mx,Os, 25/18V, 500MHz		7d	SOT-30	BF 324	7a	BF 324, BF 414, BF 506, BF 914, BF 936
BF 340	Tix	Si-P	AM Inp,Mx,Os,IF, 35V, >80MHz, F=1dB(1MHz), hFE>30		7d	SOT-30	BF 324	7a	BF 324, BF 440...441, BF 450...451, ++
BF 341	Tix	Si-P	=BF 430: hFE=45...150		7d	SOT-30	BF 324	7a	BF 324, BF 440...441, BF 450...451, ++
BF 342	Tix	Si-P	=BF 340: hFE=60...150		7d	SOT-30	BF 324	7a	BF 324, BF 440...441, BF 450...451, ++
BF 343	Tix	Si-P	=BF 340: hFE>30		7d	SOT-30	BF 324	7a	BF 324, BF 440...441, BF 450...451, ++
BF 344	Sgs	Si-N	AM Inp,Mx,Os,IF, 30/20V, 500MHz, F=2dB(1MHz)		2d	TO-18	BF 255	7d	BF 240...241, BF 254...255, BF 494...495,++
BF 345	Sgs	Si-N	AM Inp,Mx,Os,IF, 30/20V, 500MHz, F=2dB(1MHz)		2d	TO-18	BF 255	7d	BF 240...241, BF 254...255, BF 494...495,++
BF 346	Tix	N-FET	VHF, In, 15V, Idss=2...80mA, Up=0,5...5,5V, 500MHz		7f	SOT-30			BF 256, BFS 71, 2N3822, 2N4416, ++
BF 347	Tix	N-FET	LF,HF, 30V, Idss=0,5...2,5mA, Up<0,5V		7e	TO-92			BFW 13, 2N4338, 2SK68, 2SK106, 2SK118,++
BF 348	Tix	N-FET	FM/VHF Inp,Mx, 40V, Idss=10...60mA, Up=1...6V		7f	TO-92			BF 256, BFT 10, 2N5397, 2N5486
BF 350	Tix	MOS-N-FET-d	Dual-Gate, VHF, 15V, Idss=3...30mA, Up<5V		5h	TO-72	BF 960	25g	BF 900, 3SK40
BF 351	Tix	MOS-N-FET-d	Dual-Gate, VHF, 24V, Idss=5...30mA, Up<5V		5h	TO-72	BF 960	25g	3N201...206, 3N209...210, 3N211...213
BF 352	Tix	MOS-N-FET-d	Dual-Gate, VHF, 24V, Idss=5...30mA, Up<2V		5h	TO-72	BF 960	25g	BF 963, 3SK51, 3SK74, 3SK81
BF 353	Tix	MOS-N-FET-d	Dual-Gate, VHF, 24V, Idss=5...30mA, Up<3V		5h	TO-72	BF 960	25g	BF 963, 3SK51, 3SK74, 3SK81
BF 354	Tix	MOS-N-FET-d	Dual-Gate, VHF, 24V, Idss=7...15mA, Up>3V		5h	TO-72	BF 960	25g	BF 963, 3SK41, 3SK74, 3SK81
BF 355	Phi,Tix	Si-N	Vid, 300/225V, 0,1A, 0,8W, >80MHz		2a	TO-39	BF 259	2a	BF 259, BF 659, 2N5058
BF 356	Tix	Si-N	Vid, 220/220V, 0,2A, 0,8W, 100MHz		7c	TO-92	BF 420 A	7c	BF 392...393, BF 420A, BF 422A, MPS-A42++
BF 357(K,S)	Tix	Si-N	UHF A, 30/15V, 0,05A, 1,6GHz, Gp=7,5dB(800MHz)		7a	SOT-30	2SC2570A	7f	BF 377...378, BF 689, BF 763, 2SC3776,++
BF 359	Sgs	Si-P	Min, UHF Inp In, 40/35V, 850MHz, F=4dB(800MHz)		(40b)				(BF 606, BF 679...680, BF 967...970, ++)[6]
BF 360	Sgs	Si-P	Min, UHF Mx,Os, 40/35V, 750MHz, Gp=10dB(800MHz)		(40b)				(BF 606, BF 679...680, BF 967...970, ++)[6]
BF 362	Aeg,Phi,++	Si-N	UHF Inp agc, 30/20V, 800MHz, F=5dB(800MHz)		24a	SOT-37	2SC2466	25p	2SC2464...66, 2SC2726, (BF 689K, BF 763)[6]
BF 363	Aeg,Phi,++	Si-N	UHF Mx, 30/20V, 700MHz, Gp=12dB(900MHz)		24a	SOT-37	2SC2466	25p	2SC2464...66, 2SC2726, (BF 689K, BF 763)[6]
BF 364	Phi,Tho	Si-N	AM Inp,Mx,Os,IF, 30/20V, 260MHz		8d	TO-106	BF 255	7d	BF 240, BF 254, BF 494, 2SC829, 2SC2210+
BF 365	Phi,Tho	Si-N	FM Inp,Mx,Os,IF, 30/20V, 200MHz		8d	TO-106	BF 255	7d	BF 241, BF 255, BF 495, 2SC829, 2SC2210+
BF 366	Mot	Si-N	FM/VHF, agc, 35/30V, >400MHz, Gp=20dB(200MHz)		7e, 7f	TO-92	2SC2570A	7f	BF 225, BF 314, BF 496, 2SC1855...56, ++
BF 367	Mot	Si-N	TV IF, agc, 40/30V, 440MHz, Gp=25dB(35MHz)		7f	TO-92	BF 198	7d	BF 198, BF 225, BF 310, 2SC1855, 2SC2215
BF 368	Mot,Mic	Si-N	AM/FM Mx,Os,IF, 25/15V, >250MHz, F=4dB(100MHz)		7e	TO-92	BF 255	7d	BF 240...241, BF 254...255, BF 494...495,++
BF 368 K		Si-N	=BF 368:		7f	TO-92	›BF 368		›BF 368
BF 369	Mot,Mic	Si-N	AM/FM Mx,Os,IF, 30/20V, >400MHz, F=4dB(100MHz)		7e	TO-92	BF 255	7d	BF 240...241, BF 254...255, BF 494...495,++
BF 369 K		Si-N	=BF 369:		7f	TO-92	›BF 369		›BF 369
BF 370(R)	Phi	Si-N	TV IF Inp (OFW/SAW-Filter), 40/15V, >500MHz		7a	TO-92	BF 959	7d	BF 920...921S, BF 959
BF 371	Mot	Si-N	TV IF, 40/30V, 100mA, 720MHz		7f	TO-92	BF 199	7d	BF 199, BF 224, BF 311, 2SC2215...16,++
BF 372	Mot,Sgs	Si-P	VHF Inp agc, 40/35V, 850MHz, F=2,7dB(200MHz)		5g	TO-72			BF 506, BF 509, BF 914, BF 939
BF 373	Mot	Si-N	TV IF, 45/45V, 100mA, 720MHz		7f	TO-92	BF 199	7d	BF 199, BF 224, BF 311, 2SC2215...16,++
BF 374	Mot	Si-N	FM/VHF, 30/25V, 100mA, >400MHz, F=4dB(100MHz)		7f	TO-92	BF 199	7d	BF 225, BF 314, BF 496, 2SC1393, 2SC1856
BF 375	Mot	Si-N	FM/VHF, 30/25V, 100mA, >400MHz, F=4dB(100MHz)		7f	TO-92	BF 199	7d	BF 225, BF 314, BF 496, 2SC1393, 2SC1856
BF 377	Aeg	Si-N	VHF/UHF, 30/15V, >1300MHz, Gp=12dB(800MHz)		7a	TO-92	2SC2570A	7f	BF 689, BF 763, 2N2857, 2SC3776...77,++
BF 378	Aeg	Si-N	=BF 377: Gp=14dB(800MHz)		7d	TO-92	2SC2570A	7f	›BF 377
BF 379	Aeg,Mot	Si-P	AM/FM, 40/25V, 350MHz, Gp>16dB(200MHz)		7a	TO-92	BF 324	7a	BF 324, BF 440...441, BF 450...451, ++
BF 380	Mot	Si-N	Vid P, 180/180V, 0,5A, 10W, 90MHz		13m	(Uniwatt)	MPS-U10	13m	MPS-U10, BF 460...462, (BF 757...759)[5]
BF 381	Mot	Si-N	=BF 380: 250/250V		13m	(Uniwatt)	MPS-U10	13m	MPS-U10, BF 460...462, (BF 757...759)[5]
BF 382	Mot	Si-N	=BF 380: 300/300V		13m	(Uniwatt)	MPS-U10	13m	MPS-U10, BF 461...462, (BF 758...759)[5]
BF 384	Tix	Si-N	AM/FM Inp,Mx,Os,IF, 30/20V, 800MHz, F=3dB(60MHz)		7d	SOT-30	BF 255	7d	BF 240...241, BF 254...255, BF 494...495,++
BF 385	Tix	Si-N	AM/FM Inp,Mx,Os,IF, 30/20V, 800MHz, F=3dB(60MHz)		7d	SOT-30	BF 255	7d	BF 240...241, BF 254...255, BF 494...495,++
BF 387	Sgs	Si-N	Vid, 100/100V, 0,05A, 0,8W, 120MHz		2a	TO-39	BF 259	2a	BF 257...259, BF 657...659, 2N5058...5059
BF 388	Sgs	Si-N	=BF 387: 160/150V		2a	TO-39	BF 259	2a	BF 257...259, BF 657...659, 2N5058...5059
BF 389 B		Si-N	=BF 387: 220V		2a	TO-39	BF 259	2a	BF 258...259, BF 658...659, 2N5058...5059
BF 389 C		Si-N	=BF 387: 250V		2a	TO-39	BF 259	2a	BF 258...259, BF 658...659, 2N5058...5059
BF 390	Sgs	Si-N	Vid, 310/180V, 0,1A, 0,6W, 120MHz		2a	TO-39	BF 259	2a	BF 259, BF 659, BFS 89, 2N5058
BF 391(K,L,M)	Mot,Sgs	Si-N	Vid, 200/200V, 0,5A, 0,625W, >50MHz		7e, 40	TO-92	BF 420 A	7c	BF 420A, BF 422A, BFP 22, MPS-A43
BF 391 P1	Tho	Si-N	=BF 391: 0,2A, 1W		30e	TO-237	MPS-U10[6]	13m	(BF 460...461, BF 757...759, MPS-U10, ++)[5]
BF 391 P2	Tho	Si-N	=BF 391: 0,2A, 1W		30b	TO-237	BF 759[6]	13h	BF 757...759, (BF 460...461, MPS-U10, ++)[5]
BF 392(K,L,M)	Mot,Sgs	Si-N	=BF 391: 250/250V		7e, 40	TO-92	BF 420 A	7c	BF 420A, BF 422A, BFP 25, MPS-A42
BF 392 P1	Tho	Si-N	=BF 392: 0,2A, 1W		30e	TO-237	MPS-U10[6]	13m	(BF 460...461, BF 757...759, MPS-U10, ++)[5]
BF 392 P2	Tho	Si-N	=BF 392: 0,2A, 1W		30b	TO-237	BF 759[6]	13h	BF 757...759, (BF 460...461, MPS-U10, ++)[5]
BF 393(K,L,M)	Mot,Sgs	Si-N	=BF 391: 300/300V		7e, 40	TO-92	BF 420 A	7c	BF 420A, BFP 25, MPS-A42
BF 393 P1	Tho	Si-N	=BF 393: 0,2A, 1W		30e	TO-237	MPS-U10[6]	13m	(BF 461, BF 758...759, MPS-U10, ++)[5]
BF 393 P2	Tho	Si-N	=BF 393: 0,2A, 1W		30b	TO-237	BF 759[6]	13h	BF 758...759, (BF 461, MPS-U10, ++)[5]
BF 394	Mot	Si-N	AM/FM Inp,Mx,Os,IF, 30/30V, 100mA, >80MHz		7f	TO-92	BF 255	7d	BF 240...241, BF 254...255, BF 494...495,++
BF 395	Mot	Si-N	AM/FM Inp,Mx,Os,IF, 30/30V, 100mA, >80MHz		7f	TO-92	BF 255	7d	BF 240...241, BF 254...255, BF 494...495,++
BF 397	Tix	Si-P	Nixie, Vid, 90/90V, 0,1A, 0,625W		7a	SOT-30	BF 421 A	7c	BF 435...437, BSS 68, 2SA1370...1371

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BF 398	Tix	Si-P	=BF 397: 150/150V		7a	SOT-30	BF 421 A	7c	BF 435…437, 2SC1370…1371
BF 400	Sgs	Si-P	VHF, 30/30V, >700MHz		8d	TO-106			BF 509, BF 606, BF 914, BF 939, ++
BF 402	Sgs	Si-P	VHF, 25/25V, >400MHz		8a	TO-106	BF 324	7a	BF 324, BF 414, BF 506, BF 914, BF 936++
BF 403	Fer	Si-N	SMD, LF, 30/20V, 0,05A, 300MHz		35d(2mm)	SOT-323			-
BF 404	Fer	Si-P	SMD, LF, 30/20V 0,05A, 150MHz		35d(2mm)	SOT-323			-
BF 405	Fer	Si-N	SMD, LF, 45/35V -/0,5A, >150MHz		35d(2mm)	SOT-323			-
BF 406	Fer	Si-P	SMD, LF, 45/35V -/0,5A, >150MHz		35d(2mm)	SOT-323			-
BF 410	Phi,Sie	N-FET	VHF, In, 20V, Idss=0,3…10mA, Up=1,5V		7f	TO-92			2N5484, 2SK152, 2SK192
BF 411	Aeg	Si-N	Nixie, 110/90V, 0,05A, 0,3W, 120MHz		7a	TO-92	BF 420 A	7c	BF 422, BF 297…299, BF 483, BSS 38
BF 412	Aeg	Si-N	=BF 411: 150/130V		7a	TO-92	BF 420 A	7c	BF 420, BF 422, BF 297…299, BF 483
BF 413	Aeg	Si-N	=BF 411: 200/170V		7a	TO-92	BF 420 A	7c	BF 420, BF 422, BF 298…299, BF 483
BF 414	Aeg,Sgs,Sie	Si-P	FM/VHF Inp, 40/30V,400MHz, F=2dB(100MHz)		7a	TO-92	BF 324	7a	BF 324, BF 506, BF 914, BF 936, BF 939++
BF 415	Tho,Tix	Si-N	Vid P, 250/250V, 0,2A, 6W, >50MHz	{BF416	14h	TO-126	BF 471	14h	BF 615, BF 757…759, (BF 460…461, ++)[5]
BF 416	Tho,Tix	Si-P	Vid P, 250/250V, 0,2A, 6W, >50MHz	{BF415	14h	TO-126	BF 472	14h	BF 616, BF 760…762, (BF 464…465, ++)[5]
BF 417(G)	Tho,Tix	Si-N	=BF 415: 300/300V	{BF418	14h	TO-126	BF 471	14h	BF 617, BF 758…759, (BF 461, ++)[5]
BF 418(G)	Tho,Tix	Si-P	=BF 416: 300/300V	{BF417	14h	TO-126	BF 472	14h	BF 618, BF 761…762, (BF 465, ++)[5]
BF 419	Phi	Si-N	Vid P,TV-HA Drv 300/250V, 0,1/0,3A, 6W(Tc=90°)		14h	TO-126	BF 459	14h	BF417, BF459, 2SC3417, 2SC3503, 2SC4147+
BF 420(S)	EUR	Si-N	Vid, 300V, 25…50mA, 0,83W, >60MHz	{BF421	7c	TO-92	BF 420 A	7c	BF 299, BF 483, 2SC3468, 2SC4218,++
BF 420 A	Sie	Si-N	=BF 420: 0,5A, 0,8W		7c	TO-92	BF 420 A	7c	BF 393, BFP 25, MPS-A42
BF 420 L	Sie	Si-N	=BF 420: 0,5A, 0,625W		7e	TO-92	BF 420 A	7c	›BF 420A
BF 420 P	Tho	Si-N	=BF 420: 0,9W		30a	TO-237	MPS-U10[6]	13m	BF 461…462, MPS-U10
BF 420 P3	Tho	Si-N	=BF 420: 0,9W		30c	TO-237	BF 759[6]	13h	(BF 461…462, BF 758…759, MPS-U10)[5]
BF 421(S)	EUR	Si-P	Vid, 300V, 25…50mA, 0,83W, >60MHz	{BF420	7c	TO-92	BF 421 A	7c	BF 437, 2SA1371…1372, 2SA1624, ++
BF 421 A	Sie	Si-P	=BF 421: 0,5A, 0,8W		7c	TO-92	BF 421 A	7c	BF 493, BFP 26, MPS-A92
BF 421 L	Sie	Si-P	=BF 421: 0,5A, 0,625W		7e	TO-92	BF 421 A	7c	›BF 421A
BF 421 P	Tho	Si-P	=BF 421: 0,9W		30a	TO-237	MPS-U60[6]	13m	BF 464…465, MPS-U60
BF 421 P3	Tho	Si-P	=BF 421: 0,9W		30c	TO-237	BF 762[6]	13h	(BF 464…465, BF 761…762, MPS-U60)[5]
BF 422(S)	EUR	Si-N	=BF 420: 250/250V	{BF423	7c	TO-92	BF 420 A	7c	BF 298…299, BF 483, 2SC3468, 2C4218,++
BF 422 A	Sie	Si-N	=BF 422: 0,5A, 0,8W		7c	TO-92	BF 420 A	7c	BF 392…393, BFP 25, MPS-A42
BF 422 L	Sie	Si-N	=BF 422: 0,5A, 0,625W		7e	TO-92	BF 420 A	7c	›BF 422A
BF 422 P	Tho	Si-N	=BF 422: 0,9W		30a	TO-237	MPS-U10[6]	13m	BF 460…462, MPS-U10
BF 422 P3	Tho	Si-N	=BF 422: 0,9W		30c	TO-237	BF 759[6]	13h	(BF 460…462, BF 757…759, MPS-U10)[5]
BF 423(S)	EUR	Si-P	=BF 421: 250/250V	{BF422	7c	TO-92	BF 421 A	7c	BF 436…437, 2SA1371…1372, 2SA1624, ++
BF 423 A	Sie	Si-P	=BF 423: 0,5A, 0,8W		7c	TO-92	BF 421 A	7c	BF 492…493, BFP 26, MPS-A92
BF 423 L	Tho	Si-P	=BF 423: 0,5A, 0,625W		7e	TO-237	BF 421 A	7c	›BF 423A
BF 423 P	Tho	Si-P	=BF 423: 0,9W		30a	TO-237	MPS-U60[6]	13m	BF 463…465, MPS-U60
BF 423 P3	Tho	Si-P	=BF 423: 0,9W		30c	TO-237	BF 762[6]	13h	(BF 463…465, BF 760…762, MPS-U60)[5]
BF 424	Itt	Si-P	HF, 30/30V, 25mA, 300MHz, F<3dB(100MHz)		7a	TO-92	BF 324	7a	BF 324, BF 440…441, BF 450…451, ++
BF 430(L)	Mot	Si-N	SMD, UHF, 20/10V, 70mA, 7,5GHz, Gp=13,5dB(1GHz)		44s	SOT-143			BFG 520, BFP 193
BF 431(L)	Mot	Si-N	SMD, UHF, 25/15V, 30mA, 3,8GHz, Gp=13,5dB(1GHz)		44s	SOT-143			BFG 93A
BF 432(L)	Mot	Si-N	SMD, UHF, 15/8V, 1mA, 5GHz, Gp=12,5dB(1GHz)		44s	SOT-143			=MRF 9331(L), BFG 92A
BF 433	Mot	Si-N	SMD, VHF/UHF, 30/15V, 200mA, 5,5GHz, F=2dB(500MHz)		8-MDIP	SO-8			=MRF 5812
BF 435	Tix	Si-P	Vid, 160/160V, 0,2A, 0,625W, >80MHz		7c	TO-92	BF 421 A	7c	BF 491…493, BFP 23, BFP 26, MPS-A92…93
BF 436	Tix	Si-P	=BF 435: 250/250V		7c	TO-92	BF 421 A	7c	BF 492…493, BFP 26, MPS-A92, 2SB918
BF 437	Tix	Si-P	=BF 435: 300/300V		7c	TO-92	BF 421 A	7c	BF 439, BFP 26, MPS-A92, 2SA1251
BF 439	Mot	Si-P	UHF Mx,Os, 20/20V, >900MHz, F<5dB(860MHz)		5g	TO-72	(BF 979(S))[4]	24e	BF 316, BF 516, BF 606, BFR 38
BF 440	Aeg	Si-P	AM/FM, agc, 40/40V, 250MHz, F=2dB(200kHz)		7d	TO-92	BF 324	7a	BF 324, BF 450, BF 540…542, BF 906,++
BF 441	Aeg	Si-P	AM/FM, 40/40V, 250MHz, F=2dB(200kHz)		7d	TO-92	BF 324	7a	BF 324, BF 451, BF 540…542, BF 906,++
BF 450	Phi,Sie,++	Si-P	AM/FM, agc, 40/40V, 375MHz, F=2dB(100kHz)		7d	TO-92	BF 324	7a	BF 324, BF 440, BF 540…542, BF 906,++
BF 451	Phi,Sie,++	Si-P	AM/FM, 40/40V, 325MHz, F=2dB(100kHz)		7d	TO-92	BF 324	7a	BF 324, BF 441, BF 540…542, BF 906,++
BF 454	Sgs	Si-N	AM/FM IF, 35/25V, 400MHz, F=3dB(100MHz)		8d	TO-106	BF 255	7d	BF 240, BF 254, BF 494, 2SC829, 2SC2210+
BF 455	Sgs	Si-N	AM/FM Inp,Mx,Os, 35/25V, 400MHz, F=3dB(100MHz)		8d	TO-106	BF 255	7d	BF 241, BF 255, BF 495, 2SC829, 2SC2210+
BF 456	Sie,Tix	Si-N	Vid P, 160/160V, 0,1A, 7W, 90MHz		14h	TO-126	BF 459	14h	BF 457…459, BF 415, 2SC3417, 2SC3601,++
BF 457	EUR	Si-N	Vid P, 160/160V, 0,1/0,3A, 10W(Tc=45°), 90MHz		14h	TO-126	BF 459	14h	BF 415, 2SC3417, 2SC3503, 2SC4147,++
BF 458	EUR	Si-N	=BF 457: 250/250V		14h	TO-126	BF 459	14h	BF 415, BF 417, 2SC3417, 2SC3503,++
BF 459	EUR	Si-N	=BF 457: 300/300V		14h	TO-126	BF 459	14h	BF 850, 2SC3417…18, 2SC3503, 2SC4147,++
BF 460	Mot,Tho	Si-N	Vid P, 250/250V, 0,5A, 10W, >45MHz	{BF463	13m	TO-202	MPS-U10	13m	MPS-U10, (BF 758…759)[5]
BF 461	Mot,Tho	Si-N	=BF 460: 300/300V	{BF464	13m	TO-202	MPS-U10	13m	MPS-U10, (BF 758…759)[5]
BF 462	Mot,Tho	Si-N	=BF 460: 350/350V		13m	TO-202	(MPS-U10)[7]	13m	(BF 759)[5]
BF 463	Mot,Tho	Si-P	Vid P, 250/250V, 0,5A, 10W, >20MHz	{BF460	13m	TO-202	MPS-U60	13m	MPS-U60, (BF 761…762)[5]
BF 464	Mot,Tho	Si-P	=BF 463: 300/300V		13m	TO-202	MPS-U60	13m	MPS-U60, (BF 761…762)[5]
BF 465	Mot,Tho	Si-P	=BF 463: 350/350V		13m	TO-202	(MPS-U60)[7]	13m	(BF 762)[5]
BF 460BA….465BA	Tho	Si-N/P	=BF 460…465: Kühlfahne gekröpft/cranked tab		13m	TO-202			›BF 460…465
BF 460EA….465EA	Tho	Si-N/P	=BF 460…465: TO-202 ohne Kühlfahne/without tab		30m				›BF 460…465
BF 466	Mot,Tho	Si-N	LF,S,Vid P, 200/150V, 1/2A, 10W, >100MHz		13m	TO-202			(BD 410, BF 666, 2SC4615…16)[5]
BF 467	Mot,Tho	Si-N	=BF 466: 250/200V		13m	TO-202			(BD 410, BF 667, 2SC4615…16)[5]
BF 468		Si-N	=BF 466: 300/250V		13m	TO-202			(BD 410, BF 668, 2SC4615…16)[5]
BF 469(S)	EUR	Si-N	Vid P, 250/250V, 0,03/0,1A, 2W(Tc=110°), >60MHz	{BF470	14h	TO-126	BF 471	14h	BF 458…459, BF 415, 2SC3424, 2SC3503,++
BF 470(S)	EUR	Si-P	Vid P, 250/250V, 0,03/0,1A, 2W(Tc=110°), >60MHz	{BF469	14h	TO-126	BF 472	14h	BF 416, 2SA1361, 2SA1353, 2SA1381,++
BF 471(S)	EUR	Si-N	=BF 469: 300V	{BF472	14h	TO-126	BF 471	14h	BF 459, BF 417, 2SC3417…3418, 2SC3503++
BF 472(S)	EUR	Si-P	=BF 470: 300V	{BF471	14h	TO-126	BF 472	14h	BF 418, 2SA1353…1354, 2SA1381
BF 479	Aeg,Sgs	Si-P	VHF/UHF Inp, 30/25V, 2GHz, F<6dB(800MHz)		24a	SOT-37	BF 979(S)	24e	BF 679, BF 967…968, BF 979
BF 479 S	Sgs	Si-P	=BF 479: 25/25V, 1300MHz, F<4,5dB(800MHz)		24a	SOT-37	BF 979(S)	24e	›BF 479
BF 479 T	Aeg	Si-P	=BF 479: 20/20V, 1850MHz, F<6dB(800MHz)		24a	SOT-37	BF 979(S)	24e	›BF 479
BF 480	Phi,Tho	Si-N	UHF Inp, 20/15V, 1500MHz, F=3,3dB(800MHz)		24e	SOT-37	2SC2466	25p	BF 362, 2SC2464…66, 2SC2726, 2SC2728,++
BF 481	Phi	Si-N	UHF Inp, 20/15V, 1200MHz, F=4dB(800MHz)		24e	SOT-37	2SC2466	25p	BF 362, 2SC2464…66, 2SC2726, 2SC2728,++
BF 483	Phi	Si-N	Vid, 300/250V, 0,05/0,1A, 0,83W, >70MHz		7c	TO-92	BF 487	7c	BF 420(A), 2SC3468…3469, 2SC4218, ++
BF 484	Phi	Si-P	Vid, 250/250V, 0,1/0,1A, 0,83W, >70MHz		7c	TO-92	BF 421A	7c	BF 421A, BF 436…437, 2SA1371, 2SA1624++
BF 485	Phi	Si-N	=BF 483: 350/300V		7c	TO-92	BF 487	7c	2SC2267, 2SC3469, 2SC4166, 2SD1385
BF 486	Phi	Si-P	=BF 484: 300/300V		7c	TO-92	BF 421A	7c	BF 421A, BF 437, 2SA1371, 2SA1624, ++
BF 487	Phi	Si-N	=BF 483: 400/350V		7c	TO-92	BF 487	7c	2SC2267, 2SC3469, 2SC4166, 2SD1385
BF 488	Phi	Si-P	=BF 484: 350/350V		7c	TO-92	BF 421A	7c	BF 493S, 2SA1251, 2SA1372, 2SB1209
BF 491(K,L,M)	Fer,Mot,Tho	Si-P	Vid, 200/200V, 0,5A, 0,625W, >50MHz	{BF391	7e, 40	TO-92	BF 421 A	7c	BF 421A, BF 423A, BFP 23, MPS-A93
BF 491 P1	Tho	Si-P	=BF 491: 0,2A, 1W		30e	TO-237	MPS-U60[6]	13m	(BF 463…464, BF 760…762, MPS-U60, ++)[5]
BF 491 P2	Tho	Si-P	=BF 491: 0,2A, 1W		30b	TO-237	BF 762[6]	13h	BF 760…762, (BF 463…464, MPS-U60, ++)[5]
BF 492(K,L,M)	Fer,Mot,Tho	Si-P	=BF 491: 250/250V	{BF392	7e, 40	TO-92	BF 421 A	7c	BF 421A, BF 423A, BFP 26, MPS-A92
BF 492 P1	Tho	Si-P	=BF 492: 0,2A, 1W		30e	TO-237	MPS-U60[6]	13m	(BF 463…464, BF 760…762, MPS-U60, ++)[5]
BF 492 P2	Tho	Si-P	=BF 492: 0,2A, 1W		30b	TO-237	BF 762[6]	13h	BF 760…762, (BF 463…464, MPS-U60, ++)[5]
BF 493(K,L,M)	Fer,Mot,Tho	Si-P	=BF 491: 300/300V		7e, 40	TO-92	BF 421 A	7c	BF 421A, BFP 26, MPS-A92
BF 493 P1	Tho	Si-P	=BF 493: 0,2A, 1W		30e	TO-237	MPS-U60[6]	13m	(BF 464, BF 761…762, MPS-U60, ++)[5]
BF 493 P2	Tho	Si-P	=BF 493: 0,2A, 1W		30b	TO-237	BF 762[6]	13h	BF 761…762, (BF 464, MPS-U60, ++)[5]

Original	Fabric.	Constr.	Info	(Compl.	Fig.		JAEGER	Fig.	International
BF 493 S	Mot	Si-P	=BF 491: 350/350V		7e(9mm)	TO-92L	BF 762[6]	13h	2SA1625, 2SA1785, 2SB1074, 2SB1488
BF 494(B)	Phi,Nsc	Si-N	AM/FM, 30V, 30mA, 0,3W, 260MHz, F=4dB(100MHz)		7d	TO-92	BF 255	7d	BF 240…241, BF 254…255, 2SC2210,++
BF 495(C)	Phi,Nsc	Si-N	AM/FM, 30V, 30mA, 0,3W, 200MHz, F=4dB(100MHz)		7d	TO-92	BF 255	7d	BF 240…241, BF 254…255, 2SC2210,++
BF 494…495 [Mot]	Mot	Si-N	=BF 494…495: 0,1A 0,35W		7e	TO-92	BF 255	7d	BF 240…241, BF 254…255, 2SC2210,++
BF 496	Phi	Si-N	VHF Inp, 30/20, 550MHz, F=2,5dB/Gp=27dB(200MHz)		7a	TO-92	BF 198	7d	BF 225, BF 314, 2SC1393, 2SC1856,++
BF 497	Sgs	Si-N	TV IF, 40/25V, 50mA, 1000MHz		8a	TO-106	BF 199	7d	BF 199, BF 224, BF 311, 2SC2215…16,++
BF 500(A)	Sgs	Si-P	VHF Inp,Mx,Os, 30/30V, 400MHz, A: F<4dB(100MHz)		8a	TO-106	BF 324	7a	BF 324, BF 414, BF 506, BF 509, BF 914++
BF 501	Sgs	Si-P	VHF In, 30/30V, 300MHz, F=1dB(500kHz)		8a	TO-106	BF 324	7a	BF 324, BF 414, BF 509, BF 914, BF 939++
BF 502	Sie	Si-N	VHF Mx,Os, 40/30V, 20mA, 700MHz, F=3<5dB(200MHz)		7d	TO-92	BF 199	7d	BF 225, BF 314, BF 496, 2SC1393, 2SC1856
BF 502 S	Tho	Si-N	=BF 502: 30mA, 900MHz, F<4dB/Gp=22dB(200MHz)		7d	TO-92	BF 199	7d	›BF 502
BF 503	Sie	Si-N	=BF 503: 750MHz		7d	TO-92	BF 199	7d	BF 225, BF 314, BF 496, 2SC1393, 2SC1856
BF 504	Ucp	Si-N	LF, 30V, 0,05A, 0,25W, 85MHz		2a	TO-5			BC 168, BC 183, BC 238, BC 548, 2SD767++
BF 505	Sie	Si-N	VHF, 30/25V, >750MHz, F=3dB(200MHz)		7d	TO-92	2SC2570A	7f	BF 502…503, BF 507, 2SC1855…56,++
BF 506	Aeg,Mot,Sie	Si-P	VHF Inp, 40/35V, 30mA, 550MHz, F=3<4dB(200MHz)		7a	TO-92	BF 324	7a	BF 324, BF 414, BF 509, BF 914, BF 936++
BF 506 A	Sgs	Si-P	=BF 506: 25/20V, 25mA, 350MHz		7a	TO-92	BF 324	7a	BF 324, BF 414, BF 509, BF 914, BF 936++
BF 506	Ucp	Si-N	LF, 45V, 0,05A, 0,25W, 95MHz		2a	TO-5			BC 167, BC 182, BC 237, BC 547, 2SD767++
BF 507	Sie	Si-N	VHF Inp,Mx, 30/25V, >750MHz, F=3dB(200MHz)		7d	TO-92	2SC2570A	7f	BF 502…503, BF 505, 2SC1393, 2SC1856,++
BF 509(S,T)	Aeg,Mot,Tho	Si-P	VHF Inp agc, 40/35V, F=2,6dB/Gp=17dB(200MHz) BF 509: 750MHz, BF 509S: 800MHz, BF 509T: 700MHz		7a	TO-92	(BF 979(S))[4]	24e	BF 506, BF 914, BF 936, BF 939
BF 510…511 [Ucp]	Ucp	Si-N	LF, 30V, 0,05A, 0,25W, 80MHz		2a	TO-5			BC 168, BC 183, BC 238, BC 548, 2SD767++
BF 510	Phi	N-FET	=BF 410A: SMD		35e	SOT-23			2SK212
BF 511	Phi	N-FET	=BF 410B: SMD		35e	SOT-23			2SK212
BF 512	Phi	N-FET	=BF 410C: SMD		35e	SOT-23			-
BF 513	Phi	N-FET	=BF 410D: SMD		35e	SOT-23			-
BF 516	Sgs	Si-P	VHF/UHF Mx,Os, 40/35V, 850MHz, Gp=14dB(800MHz)		5g	TO-72			BF 316, BF 439, BF 606, BFR 38
BF 517	Sie	Si-N	SMD, UHF A,Os, 20/15V, 25mA, 2GHz, F=5dB(800MHz)		35a	SOT-23	2SC3356	35a	BFR 35, BFT 25, 2SC3098…3099
BF 519	Ucp	Si-N	LF/HF, 70V, 0,05A, 0,3W, 150MHz		2a	TO-5			BC 174, BC 182, BC 190, BC 546, 2SC2240+
BF 520	Ucp	Si-N	LF/HF, 50V, 0,05A, 0,3W, 150MHz		2a	TO-5			BC 167, BC 182, BC 237, BC 547, 2SD767++
BF 521	Ucp	Si-N	LF/HF, 30V, 0,05A, 0,3W, 150MHz		2a	TO-5			BC 168, BC 183, BC 238, BC 548, 2SD767++
BF 523	Tix	Si-N	TV IF, 50/45V, 50mA, 500MHz		7d	SOT-30	BF 199	7d	BF 199, BF 224, BF 311, 2SC2215…16,++
BF 536	Phi,Nsc	Si-P	SMD, VHF Mx,Os, 30/30, 350MHz, Gp=17,5dB(200MHz)		35a	SOT-23			BF 568…569, BF 660
BF 540	Tix	Si-P	AM/FM, 50/45V, 50mA, 130MHz, F=1dB(1MHz), hFE>60		7d	SOT-30	BF 324	7a	BF 324, BF 440…441, BF 450…451, ++
BF 541	Tix	Si-P	=BF 540: hFE>45		7d	SOT-30	BF 324	7a	BF 324, BF 440…441, BF 450…451, ++
BF 542	Tix	Si-P	=BF 540: hFE>30		7d	SOT-30	BF 324	7a	BF 324, BF 440…441, BF 450…451, ++
BF 543	Sie	MOS-N-FET-d	=BF 544: SMD		35e	SOT-23			-
BF 544	Sie	MOS-N-FET-d	HF,20V, 30mA, Idss=1,5…6,5mA, Up=0,7<1,5V, 200MHz		7d	TO-92			-
BF 545	Phi	N-FET	=BF 245: SMD		35f	SOT-23			-
BF 547	Phi	Si-N	SMD, VHF/UHF Mx,Os, 30V, 0,03A, 1200MHz		35a	SOT-23			BFS 17
BF 547 W	Phi	Si-N	=BF 547:		35a(2mm)	SOT-323			-
BF 550	Aeg,Phi,Sie	Si-P	SMD, 40V, 25mA, HF,IF, 325MHz, F=3,4dB(100MHz)		35a	SOT-23			BF 536, BF 568…569, BF 660
BF 550 R		Si-P	=BF 550:		35d	SOT-23			BF 569R
BF 554	Sie,Tho	Si-N	SMD, AM…VHF, 30/20V, 30mA, 260MHz, F=3dB(100MHz)		35a	SOT-23			BF 599, BF 799, BFS 18….20, 2SC3015,++
BF 556	Phi	N-FET	=BF 256: SMD		35f	SOT-23			-
BF 559	Sgs	Si-P	Min, VHF, agc, 40/35V, 850MHz, F=3dB(200MHz)		(40b)				(BF 606, BF 679…680, BF 967…970, ++)[6]
BF 560	Sgs	Si-P	Min, VHF Mx,Os, 40/35V, 850MHz, Gp=19dB(200MHz)		(40b)				(BF 606, BF 679…680, BF 967…970, ++)[6]
BF 562	Sie	Si-N	VHF Inp agc, 30/20V, 600MHz, F=3dB(200MHz)		7a	TO-92	BF 198	7d	BF 225, BF 314, BF 496, 2SC1393, 2SC1856
BF 568	Sie	Si-P	SMD, VHF Inp In, 40/35V, 1100MHz, F=2,5dB(200MHz)		35a	SOT-23			BF 569, BF 579, BF 767
BF 569	Aeg,Phi,Sie	Si-P	SMD,UHF Mx,Os, 40V, 30mA, 850MHz,Gp=12,5dB(800MHz)		35a	SOT-23			BF 579, BF 767
BF 569 R		Si-P	=BF 569:		35d	SOT-23			BF 579R
BF 570	Phi	Si-N	SMD, TV IF Inp, SAW-Filter, 40V, 0,1A, >500MHz		35a	SOT-23			BF 799
BF 576	Tix	Si-P	VHF/UHF, 20/15V, 50mA, >800MHz		7c	TO-92			BF 316, BF 516, BF 606, BFR 38
BF 579	Aeg,Phi,Sie	Si-P	SMD, VHF/UHF, 20V, 30mA, 1,6GHz, Gp=16dB(800MHz)		35a	SOT-23			-
BF 579 R		Si-P	=BF 579:		35d	SOT-23			-
BF 583	Phi	Si-N	Vid P, 300/250V, 0,05/0,1A, 5W, >70MHz		13h	TO-202	BF 759	13h	BF 600, BF 617, BF 758, BF 859, BF 880++
BF 584	Phi	Si-P	Vid P, 250/250V, 0,05/0,1A, 5W, >70MHz		13h	TO-202	BF 762	13h	BF 616, BF 760, BF 848, BF 872, BF 890++
BF 585	Phi	Si-N	=BF 583: 350/300V		13h	TO-202	BF 759	13h	BF 600, BF 759, BF 880…81
BF 586	Phi	Si-P	=BF 584: 300/300V		13h	TO-202	BF 762	13h	BF 618, BF 761, BF 849, BF 890…91,++
BF 587	Phi	Si-N	=BF 583: 400/350V		13h	TO-202			BF 600, BF 881
BF 588	Phi	Si-P	=BF 584: 350/350V		13h	TO-202	BF 762	13h	BF 762, BF 890…91
BF 591	Phi	Si-N	Telecom, 210/170V, 0,15A, 1,3W(Ta=55°)		13e	TO-202			(BF 460…462, BF 615, BF 757…759, ++)[5]
BF 593	Phi	Si-N	=BF 591: 250/210V		13e	TO-202			(BF 460…462, BF 615, BF 757…759, ++)[5]
BF 594	Tix	Si-N	AM/FM, 35/25V, 30mA, 260MHz, F=4dB(100MHz), hFE>65		7d	SOT-30	BF 255	7d	BF 240…241, BF 254…255, BF 494…495,++
BF 595	Tix	Si-N	=BF 594: hFE=35…125		7d	SOT-30	BF 255	7d	BF 240…241, BF 254…255, BF 494…495,++
BF 596	Tix	Si-N	TV IF, agc, 40/30V, 25mA, 400MHz, F=3dB(35MHz)		7d	TO-92	BF 198	7d	BF 198, BF 225, BF 310, 2SC1855, 2SC2215
BF 597(A,B)	Tix	Si-N	TV IF, 40/25V, 25mA, 550MHz		7d	TO-92	BF 199	7d	BF 199, BF 224, BF 311, 2SC2215…16,++
BF 599	Aeg,Sie,Tho	Si-N	SMD, VHF, IF, 40V, 25mA, 550MHz, Gp=43dB(35MHz)		35a	SOT-23			BF 799, BFS 20, 2SC3015, 2SC3374
BF 600	Sie	Si-N	S/Vid P, 400V, 0,03A, >60MHz		13h	TO-202			BF 587, BF 881
BF 606(A,B)	Phi,Sie,Sgs	Si-P	VHF/UHF, 25/25V, 25mA, 1200MHz A: VHF Os, 40/30V, 650MHz, B: VHF-Os, 370MHz		7d	TO-92			BF 316, BF 439, BF 516, BFR 38
BF 615(BA)	Tho,Tix	Si-N	Vid P, 250/250V, 0,2/0,3A, 10W, 70MHz	(BF616	13h	TO-202	BF 759	13h	BF 757…759, (BF 460…462, MPS-U10)[5]
BF 616(BA)	Tho,Tix	Si-P	Vid P, 250/250V, 0,2/0,3A, 10W, 70MHz	(BF615	13h	TO-202	BF 762	13h	BF 760…762, (BF 463…465, MPS-U60)[5]
BF 617(BA,G)	Tho,Tix	Si-N	=BF 615: 300/300V	(BF618	13h	TO-202	BF 759	13h	BF 758…759, (BF 461…462, MPS-U10)[5]
BF 618(BA,G)	Tho,Tix	Si-P	=BF 616: 300/300V	(BF617	13h	TO-202	BF 762	13h	BF 761…762, (BF 464…465, MPS-U60)[5]
BF 615EA….618EA	Tho	Si-N/P	=BF 615…618: TO-202 ohne/without Tab		30h				›BF 615…618
BF 620	Phi	Si-N	SMD, Vid, 300/300V, 0,05/0,1A, >60MHz	(BF621	39b	SOT-89			BFN 18, BFN 20, 2SC3554, 2SC4189,++
BF 621	Phi	Si-P	SMD, Vid, 300/300V, 0,05/0,1A, >60MHz	(BF620	39b	SOT-89			BFN 19, BFN 21, 2SA1384
BF 622	Phi,Sie	Si-N	=BF 620: 250/250V	(BF623	39b	SOT-89			BFN 16, BFN 18, BFN 20, 2SC3515, 2SC4189
BF 623	Phi,Sie	Si-P	=BF 621: 250/250V	(BF622	39b	SOT-89			BFN 17, BFN 19, BFN 21, 2SA1384
BF 630	Sie	Si-N	UHF, 20/10V, 50mA, 2GHz		7a	TO-92	2SC2570A	7f	BF 377…378, BF 763, 2SC3776…77,++
BF 639	Tix	Si-P	VHF/UHF, 30/25V, 30mA, >700MHz, F<6dB(800MHz)		2a	TO-18			BF 316, BF 516, BF 606, BFR 38
BF 640	Tix	Si-P	VHF/UHF, 30/25V, 30mA, 650MHz, F=5,5dB(800MHz)		2a	TO-18			BF 316, BF 516, BF 606, BFR 38
BF 642	Mot,Tho	Si-N	Vid, 300/300V, 0,5A, 0,625W, >50MHz	(BF692	7a	TO-92	BF 420 A	7c	BF 393, BF 420A, BFP 25, MPS-A42
BF 642 P	Tho	Si-N	=BF 642: 0,9W		30a	TO-237	MPS-U10[6]	13m	BF 393P1, MPS-U10, (BF 461, BF 758…759)[5]
BF 642 P2	Tho	Si-N	=BF 642: 0,9W		30b	TO-237	MPS-U10[6]	13m	BF 393P2, BF 758…759, (BF 461, MPS-U10)[5]
BF 643	Mot,Tho	Si-N	=BF 642: 200/200V	(BF693	7a	TO-92	BF 420 A	7c	BF391…393, BF422A, BFP 22, MPS-A42…43
BF 643 P	Tho	Si-N	=BF 643: 0,9W		30a	TO-237	MPS-U10[6]	13m	BF 391P1, MPS-U10, (BF 460, BF 757…759)[5]
BF 643 P2	Tho	Si-N	=BF 643: 0,9W		30b	TO-237	MPS-U10[6]	13m	BF 391P2, BF 757…759, (BF 460, MPS-U10)[5]
BF 657	Sgs	Si-N	Vid, 160/160V, 0,1/0,2A, 1W, 90MHz		2a	TO-39	BF 259	2a	BF 257…259, 2N5058…5059
BF 658	Sgs	Si-N	=BF 657: 250/250V		2a	TO-39	BF 259	2a	BF 258…259, 2N5058…5059
BF 659	Sgs	Si-N	=BF 657: 300/300V		2a	TO-39	BF 259	2a	BF 259, BFS 89, 2N5058
BF 660	Phi,Sie	Si-P	SMD, VHF Os, 40/30V, 25mA, 650MHz		35a	SOT-23			BF 536, BF 568…569, BF 579, BF 767
BF 660 R		Si-P	=BF 660:		35d	SOT-23			BF 569R, BF 579R
BF 666	Mot	Si-N	Vid P, 200/150V, 1/2A, 10W, >100MHz		13h	TO-202	(BF 759)[7]	13h	BD 410, (BF 466…468)[5]

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
BF 667	Mot	Si-N	=BF 666: 250/200V		13h	TO-202	(BF 759)[7]	13h	BD 410, (BF 467…468)[5]
BF 668	Mot	Si-N	=BF 666: 300/250V		13h	TO-202	(BF 759)[7]	13h	BD 410, (BF 468)[5]
BF 679(M,S,T)	Aeg,Sgs	Si-P	UHF Inp agc, 40/35V, 930…1000MHz, F<5dB(800MHz)		24e	≈SOT-37	BF 979(S)	24e	BF 479, BF 779, BF 967…968, BF 979
BF 680(A,H)	Aeg,Sgs	Si-P	UHF Mx,Os, 40/35V, 650…750MHz, Gp=14dB(800MHz)		24e	≈SOT-37	BF 979(S)	24e	BF 780, BF 967, BF 969…970, BF 970
BF 681	Aeg	Si-P	UHF, 40/35V, 950MHz, F=4,3dB(800MHz)		24e	≈SOT-37	BF 979(S)	24e	BF 479, BF 779…780, BF 967…970, BF 979
BF 689	Sie	Si-N	UHF, 25/15V, 1000MHz, F=3dB/Gp=16dB(200MHz)		5g	TO-72	2SC2570A	7f	BF 377…378, BF 763, 2N2857, 2SC3776…77
BF 689 K	Phi,Sie	Si-N	=BF 689: 1800MHz		7a	TO-92	2SC2570A	7f	BF 377…378, BF 763, 2SC3776…77,++
BF 692	Mot,Tho	Si-P	Vid, 300/300V, 0,5A, 0.625W, >50	{BF642	7a	TO-92	BF 421 A	7c	BF 493, BF 421A, BFP 26, MPS-A92
BF 692 P	Tho	Si-P	=BF 692: 0.9W		30a	TO-237	MPS-U60[6]	13m	BF 493P1, MPS-U60, (BF 464, BF 761…762)[5]
BF 692 P2	Tho	Si-P	=BF 692: 0,9W		30b	TO-237	MPS-U60[6]	13m	BF 493P2, BF 761…762, (BF 464, MPS-U60)[5]
BF 693	Mot,Tho	Si-P	=BF 692: 200/200V	{BF643	7a	TO-92	BF 421 A	7c	BF491…493, BF423A, BFP23, MPS-A92…93
BF 693 P	Tho	Si-P	=BF 693: 0.9W		30a	TO-237	MPS-U60[6]	13m	BF 491P1, MPS-U60, (BF 463, BF 760…762)[5]
BF 693 P2	Tho	Si-P	=BF 693: 0.9W		30b	TO-237	MPS-U60[6]	13m	BF 491P2, BF 760…762, (BF 463, MPS-U60)[5]
BF 694(A,B)	Tix	Si-N	TV IF, 45/30V, 50mA, 300MHz		7d	TO-92	BF 199	7d	BF 199, BF 224, BF 311, 2SC2215…16,++
BF 706	Mot	Si-P	AM/FM, 30/25V, 50mA, >200MHz		7e	TO-92	BF 324	7a	BF 324, BF 440…411, BF 450…451, ++
BF 709	Mot	Si-P	FM Inp agc, 30/30V, 50mA, >350MHz, F<6,5dB(200MHz)		7e	TO-92	BF 324	7a	BF 324, BF 414, BF 506, BF 914, BF 936++
BF 715(BA)	Tho,Tix	Si-N	Vid P, 250/250V, 0,03/0,1A, 6,25W, >60MHz	{BF716	13h	TO-202	BF 759	13h	BF 858…859, BF 869, BF 861, BF 880
BF 716(BA)	Tho,Tix	Si-P	Vid P, 250/250V, 0,03/0,1A, 6,25W, >60MHz	{BF715	13h	TO-202	BF 762	13h	BF 848…849, BF 870, BF 872, BF 890
BF 717(BA)	Tho,Tix	Si-N	=BF 715: 300/300V	{BF718	13h	TO-202	BF 759	13h	BF 859, BF 871, BF 880
BF 718(BA)	Tho,Tix	Si-P	=BF 716: 300/300V	{BF717	13h	TO-202	BF 762	13h	BF 849, BF 872, BF 890
BF 715EA…718EA	Tho	Si-N/P	=BF 715…718: TO-202 ohne/without Tab		30h		BF 759/762[6]	13h	›BF 715…718
BF 720	Phi,Sie	Si-N	=BF 620: 0,05A, 1,5W	{BF721	≈39°j	SOT-223			-
BF 721	Phi,Sie	Si-P	=BF 621: 0,05A, 1,5W	{BF720	≈39°j	SOT-223			-
BF 722	Phi,Sie	Si-N	=BF 622: 0,05A, 1,5W	{BF723	≈39°j	SOT-223			-
BF 723	Phi,Sie	Si-P	=BF 623: 0,05A, 1,5W	{BF722	≈39°j	SOT-223			-
BF 739	Mot	Si-P	VHF, 20/20V, 50mA, >600MHz, F<6.5dB(850MHz)		7e°	TO-92			BF 316, BF 516, BF 606, BF 939, BFR 38
BF 740	Mot	Si-P	VHF/UHF, agc, 20/20V, 50mA, >600MHz		7e°	TO-92			BF 316, BF 516, BF 606, BFR 38
BF 747 [Phi]	Phi	Si-N	SMD, VHF/UHF Tuner, Mx,Os, 30V, -/50mA, 1200MHz		35a	SOT-23	2SC3356	35a	BF 775
BF 747 [Eiy]	Eiy	Si-P	20V, 0,1A 0,2W, 600MHz						-
BF 749	Phi	Si-N	SMD, UHF Wideband, 20V, 25mA, 5GHz, F=3dB(2GHz)		44u	SOT-143R			-
BF 750	Phi	Si-N	SMD, SATV Tuner, 15V, 35mA, 7GHz, F=1,9dB(1GHz)		44u	SOT-143R			-
BF 752	Phi	Si-N	SMD, UHF Wideband, 15V, 35mA, 7GHz, F=3dB(1GHz)		44s	SOT-143			-
BF 753	Phi	Si-N	SMD, UHF 5V-Tuner, 15V, 35mA, 5GHz, F=1,8dB(1GHz)		35a	SOT-143			-
BF 757	Mot,Nsc,Tho	Si-N	Vid P, 250/250V, 0,5/0,7A, 10W, >45MHz	{BF760	13h	TO-202	BF 759	13h	(BF 460…462, MPS-U10)[5]
BF 758	Mot,Nsc,Tho	Si-N	=BF 757: 300/300V	{BF761	13h	TO-202	BF 759	13h	(BF 461…462, MPS-U10)[5]
BF 759	Mot,Nsc,Tho	Si-N	=BF 757: 350/350V	{BF762	13h	TO-202	BF 759	13h	(BF 462)[5]
BF 760	Mot,Nsc,Tho	Si-P	Vid P, 250/250V, 0,5/0,7A, 10W, >20MHz	{BF757	13h	TO-202	BF 762	13h	2SA1156, (BF 463…465, MPS-U60)[5]
BF 761	Mot,Nsc,Tho	Si-P	=BF 760: 300/300V	{BF758	13h	TO-202	BF 762	13h	2SA1156, (BF 464…465, MPS-U60)[5]
BF 762	Mot,Nsc,Tho	Si-P	=BF 760: 350/350V	{BF759	13h	TO-202	BF 762	13h	2SA1156, (BF 465)[5]
BF 757BA…762BA	Tho	Si-N/P	=BF 757…762: Tab f. Flachmontage/flat mounting		13h	TO-202	BF 757/762	13h	›BF 757…762
BF 757EA…762EA	Tho	Si-N/P	=BF 757…762: TO-202 ohne/without Tab		30h		BF 757/762[6]	13h	›BF 757…762
BF 763	Phi,Sie	Si-N	UHF Inp,Mx,Os, 25/15V, 25mA, 1800MHz,F=5dB(800MHz)		7f	TO-92	2SC2570A	7f	BF377…78, BF689K, 2SC2570(A), 2SC3776++
BF 767	Phi,Sie	Si-P	SMD, VHF/UHF, In, 30V, 20mA, 950MHz, F=3,7dB(800M)		35a	SOT-23			BF 568…569, BF 579
BF 770 A	Sie	Si-N	SMD,UHF A,IF, 15V, 50mA, 5,5GHz, Gp=13,5dB(800MHz)		35a	SOT-23	2SC3356	35a	2SC3513, 2SC3704
BF 771	Sie	Si-N	SMD,SATV/VCR-Tuner, 20V, 80mA, 7GHz, F=1,7dB(800M)		35a	SOT-23			BFR 193, BFR 520, 2SC3445
BF 772	Sie	Si-N	=BF 771:		44s	SOT-143			BFG 520, BFP 193
BF 775	Sie	Si-N	SMD, SATV Tuner, 20V, 0,03A, 4,5GHz, F=1,5dB		35a	SOT-23	2SC3356	35a	BF 747, BFQ 29, BFT 75, 2SC3110,++
BF 775 A		Si-N	=BF 775: 25V, 4200…5800MHz, F=1,4dB(800MHz)		35a	SOT-23	2SC3356	35a	BFQ 81, BFR 93, 2SC3110, 2SC3513
BF 777	Sie	Si-N	SMD, VHF/UHF Os, 30/20V, 50mA, 2,2GHz		35a	SOT-23	2SC3356	35a	BF 747, BF 775, BFR 53, 2SC3014, 2SC3773
BF 779	Tix	Si-P	UHF Inp, 30/25V, 20mA, 800MHz		24e	TO-50	BF 979(S)	24e	BF 479, BF 679, BF 967…968, BF 979
BF 780	Tix	Si-P	UHF Mx,Os, 25/20V, 20mA, 700MHz		24e	TO-50	BF 979(S)	24e	BF 680, BF 967, BF 969…970
BF 787	Mot	Si-N	Vid P, 250/250V, 0,1/0,2A, 10W, >60MHz	{BF790	13h	TO-202	BF 759	13h	BF 615, BF 858…859, BF 880…881, ++
BF 788	Mot	Si-N	=BF 787: 300/300V	{BF791	13h	TO-202	BF 759	13h	BF 617, BF 859, BF 880…881
BF 789	Mot	Si-N	=BF 787: 350/350V	{BF792	13h	TO-202	BF 759	13h	BF 880…881
BF 790	Mot	Si-P	Vid P, 250/250V, 0,1/0,2A, 10W, >60MHz	{BF787	13h	TO-202	BF 762	13h	BF 616, BF 848…849, BF 890…891, ++
BF 791	Mot	Si-P	=BF 790: 300/300V	{BF788	13h	TO-202	BF 762	13h	BF 618, BF 849, BF 890…891
BF 792	Mot	Si-P	=BF 790: 350/350V	{BF789	13h	TO-202	BF 762	13h	BF 890…891
BF 799	Sie	Si-N	SMD,TV IF(SAW Filter), 800…1100MHz, F=3dB(100MHz)		35a	SOT-23			BF 570
BF 800	Tix	N-FET	LF,HF, 25V, Idss=0,3…1,2mA, Up<6V		5k	TO-72			-
BF 801	Tix	N-FET	LF,HF, 25V, Idss=0,3…1,2mA, Up<6V		5k	TO-72			-
BF 802	Tix	N-FET	LF,HF, 25V, Idss=0,3…1,2mA, Up<6V		5k	TO-72			-
BF 803	Tix	N-FET	LF,HF, 30V, Idss<0,8mA, Up<3V		5k	TO-72			-
BF 804	Tix	N-FET	LF,HF, 30V, Idss<1,2mA, Up<5V		5k	TO-72			-
BF 805	Tix	N-FET	LF,HF, 30V, Idss=3…13mA, Up<6V		5k	TO-72			-
BF 806	Tix	N-FET	LF,HF, 30V, Idss=3…13mA, Up<6V		5k	TO-72			-
BF 808	Tix	N-FET	LF,HF, 20V, Idss=1…6mA, Up<5V		5k	TO-72			-
BF 810(A)	Tix	N-FET	LF,HF, 30V, Idss=5…20mA, Up<6V		5k	TO-72			-
BF 811(A)	Tix	N-FET	LF,HF, 30V, Idss=5…20mA, Up<6V		5k	TO-72			-
BF 815	Tix	N-FET	LF,HF, 30V, Idss=15…40mA, Up<6V		5k	TO-72			-
BF 816	Tix	N-FET	LF,HF, 30V, Idss=15…40mA, Up<6V		5k	TO-72			-
BF 817	Tix	N-FET	LF,HF, 25V, Idss=10…40mA, Up<5V		5k	TO-72			-
BF 818	Tix	N-FET	LF,HF, 25V, Idss=10…40mA, Up<5V		5k	TO-72			-
BF 819	Phi	Si-N	Vid P, TV-HA Drv, 300/250V, 0,1/0,3A, 6W(Tc=75°)		13h	TO-202	BF 759	13h	BF 617, BF 758, BF 859, BF 880…881,++
BF 819 A		Si-N	=BF 819:		13m	TO-202	MPS-U10	13m	BF 461, MPS-U10, 2SC1758[5]
BF 820(S)	Aeg,Phi	Si-N	SMD, Vid, 300V, 25…50mA, >60MHz	{BF821	35a	SOT-23			BFN 26, 2SC4061, 2SC4412, 2SC4497
BF 821(S)	Aeg,Phi	Si-P	SMD, Vid, 300V, 25…50mA, >60MHz	{BF820	35a	SOT-23			BFN 27, 2SA1682, 2SA1721
BF 822(S)	Aeg,Phi	Si-N	=BF 820: 250/250V	{BF823	35a	SOT-23			BFN 22, BFN 24, BFN 26, 2SC4412, ++
BF 823(S)	Aeg,Phi	Si-P	=BF 822: 250/250V	{BF822	35a	SOT-23			BFN 23, BFN 25, BFN 27, 2SC1682,++
BF 824	Phi	Si-P	SMD, FM Inp, 30V, 25mA, 450MHz, F=3,5dB(100MHz)		35a	SOT-23			BF 568
BF 840	Phi,Sie,++	Si-N	=BF 240: SMD		35a	SOT-23			BF 554, BFS 18…19
BF 841	Phi,Sie,++	Si-N	=BF 241: SMD		35a	SOT-23			BF 554, BFS 18…19
BF 844	Mot	Si-N	Vid, 450/400V, 0,3A, 0,625W, >50MHz		7e	TO-92			MPS-A44, 2SD1350A
BF 845	Mot	Si-N	=BF 844: 400/350V		7e	TO-92			MPS-A44…45, 2SD1350
BF 847	Sie	Si-P	Vid P, 160/160V, 0,1/0,3A, 2,5W(Tc=100°),90MHz	{BF857	13h	TO-202	BF 762	13h	BF 616, BF 760…762, BF 890…891
BF 848	Sie	Si-P	=BF 847: 270/250V	{BF858	13h	TO-202	BF 762	13h	BF 618, BF 761…762, BF 890…891
BF 849	Sie	Si-P	=BF 847: 300/300V	{BF859	13h	TO-202	BF 762	13h	BF 761…762, BF 890…891
BF 850	Sie	Si-N	Vid P, 400V, 0,1A, >90MHz		14h	TO-126			2SC3418
BF 857(A)	Phi,Sie,Tho	Si-N	Vid P, 160/160V, 0,2/0,5A, 6W(Tc=60°), 100MHz	{BF847	13h	TO-202	BF 759	13h	BF 615, BF 757…759, BF 880…881
BF 858(A)	Phi,Sie,Tho	Si-N	=BF 857: 270/250V	{BF848	13h	TO-202	BF 759	13h	BF 617, BF 758…759, BF 880…881
BF 859(A)	Phi,Sie,Tho	Si-N	=BF 857: 300/300V	{BF849	13h	TO-202	BF 759	13h	BF 758…759, BF 880…881
BF 857BA…859BA	Tho	Si-N	=BF 857…859: Tab f. Flachmontage/flat mounting		13h	TO-202	BF 759	13h	›BF 857…859

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BF 857EA…859EA	Tho	Si-N	=BF 857…859: TO-202 ohne/without Tab		30h		BF 759[6]	13h	›BF 857…859
BF 860	Sie	Si-N	Vid P, 400V, 0,1A, >90MHz						(BF 850, BF 881)
BF 869(A,S,SA)	Aeg,Phi,++	Si-N	Vid P, 250/250V, 0,05/0,1A, 5W, >60MHz	{BF870	13h	TO-202	BF 759	13h	BF 583, BF 615, BF 858…859, BF 880…881
BF 870(A,S,SA)	Aeg,Phi,++	Si-P	Vid P, 250/250V, 0,05/0,1A, 5W, >60MHz	{BF869	13h	TO-202	BF 762	13h	BF 616, BF 848…849, BF 890…891
BF 871(A,S,SA)	Aeg,Phi,++	Si-N	=BF 869: 300V	{BF872	13h	TO-202	BF 759	13h	BF 583, BF 617, BF 859, BF 880…881
BF 872(A,S,SA)	Aeg,Phi,++	Si-P	=BF 870: 300V	{BF871	13h	TO-202	BF 762	13h	BF 618, BF 849, BF 890…891
BF 869BA…872BA	Tho	Si-N/P	=BF 869…872: Tab f. Flachmontage/flat mounting		13h	TO-202	BF 759/762	13h	›BF 869…872
BF 869EA…872EA	Tho	Si-N/P	=BF 869…872: TO-202 ohne/without Tab		30h		BF 759/762[6]	13h	›BF 869…872
BF 873 A…C	Phi	Si							
BF 874 A…C	Phi	Si							
BF 876		Si-P			13h		BF 762	13h	
BF 879	Sie	Si-P	VHF/UHF, 40/35V, 30mA		24e	≈SOT-37	BF 979(S)	24e	BF 479, BF 679…680, BF 967…970, ++
BF 880	Sie	Si-N	Vid P, 350V, 0,1A, >60MHz	{BF890	13h	TO-202	BF 759	13h	BF 850, 2SC3418
BF 881	Sie	Si-N	=BF 880: 400V	{BF891	13h	TO-202	(BF 759)[7]	13h	BF 850, 2SC3418
BF 883(S)	Aeg	Si-N	Vid P, 300/275V, 0,05A, 7W, >60MHz		13h	TO-202	BF 759	13h	BF 759, BF 859, BF 880…881
BF 885(S)	Aeg	Si-N	Vid P, 300V, 0,05A, 7W, >60MHz		13h	TO-202	BF 759	13h	BF 759, BF 859, BF 880…881
BF 890	Sie	Si-P	Vid P, 350V, 0,1A, >60MHz	{BF880	13h	TO-202	BF 762	13h	BF 762, 2SA1156, 2SA1354, 2SB1011
BF 891	Sie	Si-P	Vid P, 400V, 0,03A, >60MHz	{BF881	13h	TO-202	2SA1156	14h	2SA1156, 2SA1354, 2SB1011
BF 900	Mot,Tix	MOS-N-FET-d*	Dual-Gate, VHF/UHF, 20V, 50mA, Idss=3…30mA, Up<5V		25g	≈SOT-103	BF 960	25g	BF 960, BF 965…966
BF 901	Phi	MOS-N-FET-e*	Dual-Gate, VHF/UHF, 12V, 30mA, Idss=2…18mA		44g	SOT-143			-
BF 901 R	Phi	MOS-N-FET-e*	=BF 901:		44l	SOT-143			-
BF 904	Phi	MOS-N-FET-e	Dual-Gate, VHF/UHF, 7V, 30mA, 8…13mA, Up=0,3V		44g	SOT-143			-
BF 904 R	Phi	MOS-N-FET-e	=BF 904:		44l	SOT-143			-
BF 905	Tix	MOS-N-FET-d*	Dual-Gate, UHF, 20V, 40mA, Idss=2…25mA, Up<5V		25g	≈SOT-103	BF 960	25g	BF 900, BF 960, BF 965…966
BF 906	Mot,Tix	Si-P	AM/FM, 30/25V, 50mA, >200MHz		7a	TO-92	BF 324	7a	BF 324, BF 440…441, BF 450…451, ++
BF 907	Tix	MOS-N-FET-d*	Dual-Gate, UHF, 20V, 40mA, Idss=2…20mA, Up<3,5V		25g	≈SOT-103	BF 960	25g	BF 900, BF 960, BF 965…966
BF 908	Phi	MOS-N-FET-e	Dual-Gate, VHF/UHF, 12V, 40mA, Idss=3…27mA		44g	SOT-143			-
BF 908 R	Phi	MOS-N-FET-e	=BF 908:		44l	SOT-143			-
BF 910	Aeg,Tix	MOS-N-FET-d*	Dual-Gate, VHF/UHF, 20V, 50mA, Idss=6…40mA		25g	≈SOT-103	BF 960	25g	BF 900, BF 960, BF 965…966
BF 914	Aeg	Si-P	FM/VHF Inp, 40/35V, 25mA, 850MHz, F<3,5dB(200MHz)		7a	TO-92	BF 324	7a	BF 324, BF 414, BF 506, BF 509, BF 939++
BF 915	Tix	MOS-N-FET-d*	Dual-Gate, VHF/UHF, 18V, Idss=15…45mA, Up<4V		25g	≈SOT-103	(BF 960)	25g	(BF 900, BF 960, BF 965…966)
BF 920	Tix	Si-N	VHF/UHF, TV IF(OFW/SAW-Filter), 30V, 50mA, 1800MHz		24e	≈SOT-37	BF 959	7d	BF 921S, BF 959
BF 920 TS…923 TS	Aeg	Si-N/P	=BF 420…423: 0,46W		7e	TO-92	›BF 420…423		›BF 420…423
BF 921(S)	Sgs,Tix	Si-N	VHF/UHF, TV IF(OFW/SAW-Filter), 25V, 50mA, 1800MHz		7d	TO-92	BF 959	7d	BF 920, BF 959
BF 926	Phi,Sie	Si-P	FM/VHF Inp,Mx,Os, 30V, 500MHz, Gp=17,5dB(200MHz)		7d	TO-92	BF 324	7a	BF 324, BF 414, BF 506, BF 914, BF 936++
BF 930	Sie	MOS-N-FET-d	SMD, Dual-Gate, 12V, 40mA		44g	SOT-143			-
BF 936	Mot,Nsc,Phi	Si-P	FM/VHF, 30/20V, 25mA, 350MHz, Gp=17,5dB(200MHz)		7a	TO-92	BF 324	7a	BF 324, BF 414, BF 506, BF 509, BF 914++
BF 939	Phi,Sie	Si-P	FM/VHF Inp agc, 30/25V, 20mA, 750MHz,F<4dB(200MHz)		7a	TO-92	BF 324	7a	BF 324, BF 414, BF 506, BF 509, BF 914++
BF 959	Aeg,Mot,Sie	Si-N	VHF,TV IF(OFW/SAW-Filter), 30/20V, -/0,1A, 1100MHz		7d	TO-92	BF 959	7d	BF 920, BF 921S
BF 960(S)	EUR	MOS-N-FET-d*	Dual-Gate, UHF, 20V, 30mA, Idss=2…20mA, Up<2,7V		25g	SOT-103	BF 960	25g	BF 900, BF 965…966
BF 961	EUR	MOS-N-FET-d*	Dual-Gate, FM/VHF, 20V, 30mA, Idss=2…25mA, Up<4V		25g	SOT-103	BF 960	25g	BF 963…964, BF 981…982, ++
BF 962	Sie	MOS-N-FET-d*	Dual-Gate, VHF CATV, 20V, 30mA		25g	SOT-103	BF 960	25g	BF 961, BF 963…964, BF 981…982, ++
BF 963	Aeg	MOS-N-FET-d*	Dual-Gate,FM/VHF, 20V, 50mA, Idss=6…40mA, Up<3,5V		25g	SOT-103	(BF 960)	25g	BF 961, BF 964, BF 981…982, ++
BF 964(S)	Aeg,Phi,Sie	MOS-N-FET-d*	Dual-Gate,FM/VHF, 20V, 30mA, Idss=2…40mA, Up<2,5V		25g	SOT-103	BF 960	25g	BF 961, BF 963, BF 981…982, ++
BF 965	Sie	MOS-N-FET-d*	HF, 10V, Ids=30mA, Up<4V		7d	TO-62			-
BF 965	Aeg,Phi,Sie	MOS-N-FET-d*	Dual-Gate, CATV-Tuner, 20V, 30mA, Idss=2…20mA		25g	SOT-103	BF 960	25g	BF 960, BF 966
BF 966(S)	Aeg,Phi,Sie	MOS-N-FET-d*	Dual-Gate, UHF, 20V, 30mA, Idss=2…20mA, Up<2,5V		25g	SOT-103	BF 960	25g	BF 900, BF 960, BF 965
BF 967	Phi,Sie	Si-P	UHF Inp,Mx, agc, 30V, 20mA, 900MHz, F<5dB(800MHz)		24e	SOT-37	BF 979(S)	24e	BF 479, BF 679…680, BF 779, BF 979
BF 968	Sie	Si-P	UHF Inp agc, 40/35V, 30mA, 1100MHz, F<4dB(800MHz)		24e	SOT-37	BF 979(S)	24e	BF 479, BF 679, BF 779, BF 979
BF 969(S)	Sie	Si-P	UHF Mx,Os, 40/35V, 30mA, 850MHz, Gp=13dB(800MHz)		24e	SOT-37	BF 979(S)	24e	BF 479, BF 679…680, BF 779, BF 979
BF 970(A)	Aeg,Phi,++	Si-P	UHF Mx,Os, 40/35V, 30mA, 900MHz, Gp=14,5dB(800MHz)		24e	SOT-37	BF 979(S)	24e	BF 479, BF 679…680, BF 779, BF 979
BF 979(S)	Aeg,Phi,++	Si-P	UHF Inp, 20/20V, 30mA, 1350MHz, F<6dB(800MHz) BF 979S: 30/25V, 1600MHz, F<4,5dB(800MHz)		24e	SOT-37	BF 979(S)	24e	BF 479
BF 980(A)	Phi	MOS-N-FET-d*	Dual-Gate, UHF, 18V, 30mA, Up<1,3V		25g	SOT-103	BF 960	25g	BF 960, BF 965…966
BF 981	Phi,Tho	MOS-N-FET-d*	Dual-Gate,FM/VHF, 20V, 20mA, Idss=4…25mA, Up<2,5V		25g	SOT-103	BF 960	25g	BF 961, BF 963…964, BF 982, ++
BF 982(T)	Aeg,Phi	MOS-N-FET-d*	Dual-Gate,FM/VHF, 20V, 40mA, Idss=4…20mA, Up<1,3V		25g	SOT-103	BF 960	25g	BF 961, BF 963…964, BF 981, ++
BF 987	Aeg,Sie	MOS-N-FET-d	FM/VHF, 20V, 30mA, Idss=5…18mA, Up<2,5V		7d	TO-92			-
BF 988	Aeg,Phi,Sie	MOS-N-FET-d*	Dual-Gate, UHF, 12V, 30mA, Idss=2…18mA, Up<2,5V		25g	SOT-103	BF 960	25g	BF 960, BF 965…966
BF 989(S)	Aeg,Phi,Sie	MOS-N-FET-d*	=BF 960: SMD		44g	SOT-143			BF 996
BF 990(A)	Phi	MOS-N-FET-d*	=BF 980(A): SMD		44g	SOT-143			BF 989, BF 996
BF 990 AR		MOS-N-FET-d*	=BF 980(A): SMD		44(SG1G2D)	SOT-143R			-
BF 991	Phi	MOS-N-FET-d*	=BF 981: SMD		44g	SOT-143			BF 993, BF 994
BF 992(T)	Phi	MOS-N-FET-d*	=BF 982(T): SMD		44g	SOT-143			BF 993, BF 994
BF 992 R		MOS-N-FET-d*	=BF 982: SMD		44(SG1G2D)	SOT-143R			-
BF 993	Aeg,Sie	MOS-N-FET-d*	=BF 963: SMD		44g	SOT-143			BF 991, BF 994
BF 994(S)	Aeg,Phi,Sie	MOS-N-FET-d*	=BF 964: SMD		44g	SOT-143			BF 991, BF 993
BF 994 R		MOS-N-FET-d*	=BF 964: SMD		44(SG1G2D)	SOT-143R			-
BF 995	Aeg,Sie	MOS-N-FET-d*	=BF 965: SMD		44g	SOT-143			BF 991, BF 993, BF 994
BF 996(S)	Aeg,Phi,Sie	MOS-N-FET-d*	=BF 966: SMD		44g	SOT-143			BF 989, BF 990
BF 996 R		MOS-N-FET-d*	=BF 966: SMD		44(SG1G2D)	SOT-143R			-
BF 997	Aeg,Phi,Sie	MOS-N-FET-d*	=BF 965: SMD		44g	SOT-143			BF 989, BF 996
BF 998	Aeg,Phi,Sie	MOS-N-FET-d	=BF 988: SMD		44g	SOT-143			-
BF 999	Aeg,Sie	MOS-N-FET-d	=BF 987: SMD		35e	SOT-23			-
BF 1005	Sie	MOS-N-FET-d	SMD, Dual-Gate, UHF, 5V, 10mA, F=1dB(800MHz)		44g	SOT-143			-
BF 1012	Sie	MOS-N-FET-d	SMD, Dual-Gate, UHF, 12V, 10mA, F=1dB(800MHz)		44g	SOT-143			-
BFC 520	Ucp	Si-N	40V, 0,2A, 0,24W, 150MHz						-
BFE 182	Sie	Si-N	=BFR 182:		44(EEBC)	SOT-143			-
BFE 183	Sie	Si-N	=BFR 183:		44(EEBC)	SOT-143			-
BFE 193	Sie	Si-N	=BFR 193:		44(EEBC)	SOT-143			-
BFE 196	Sie	Si-N	=BFP 196:		44(EEBC)	SOT-143			-
BFG									
BFG 16 A	Phi	Si-N	UHF Wideband, 40V, 0,15A, 1,6GHz, Gp=10dB(500MHz)		≈39°s	SOT-223			-
BFG 17 A	Phi	Si-N	SMD, UHF A, 25V, 25mA, 2,8GHz, Gp=15dB(800MHz)		44(EEBC)	SOT-143			-
BFG 19 S	Sie	Si-N	UHF A, 20V, 0,1A, 5,3GHz, Gp=13dB(900MHz)	{BFG194	≈39°s	SOT-223			-
BFG 23	Phi	Si-P	VHF/UHF A, 15/12V, 35mA, 5GHz, Gp=14,5dB(800MHz)		24q	SOT-103			BFQ 75…76
BFG 25(A,X)	Phi	Si-N	SMD, UHF Wideband, 8V, 6,5mA, 5GHz, Gp=18dB(1GHz)		44s	SOT-143			-
BFG 31	Phi	Si-P	UHF Wideband, 20V, 0,1A, 5GHz, Gp=12dB(800MHz)		≈39°s	SOT-223			BFG 55
BFG 32	Phi	Si-P	VHF/UHF A, 20/15V, 75mA, 4,5GHz, Gp=13dB(800MHz)		24q				BFQ 194
BFG 33	Phi	Si-N	SMD, UHF Wideband, 9V, 20mA, 12GHz,Gp=12,5dB(2GHz)		44(EEBC)	SOT-143			-
BFG 33 X		Si-N	=BFG 33:		44s	SOT-143			-
BFG 34	Phi	Si-N	VHF/UHF A, 25/18V, 150mA, 3,7GHz, Gp=14dB(800MHz)		24q	SOT-103			BFG 96
BFG 35	Phi	Si-N	VHF/UHF A, 25V, 0,15A, 4GHz, Gp=11dB(800MHz)	{BFG55	≈39°s	SOT-223			BFG 135

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
BFG 51	Phi	Si-P	VHF/UHF A, 20/15V, 25mA, 5GHz, Gp=17dB(800MHz)		24q	SOT-103		BFQ 75...76
BFG 55	Phi	Si-P	UHF A, 25/18V, 0,15A, 4GHz, Gp=11dB(800MHz)		≈39°s	SOT-223		BFG 31
BFG 65(T)	Aeg,Phi	Si-N	UHF A, 20/10V, 50mA, 7,5GHz, Gp=10,5dB(2GHz)		24q	SOT-103		BFQ 65...66, 2SC3062, 2SC3584
BFG 67	Aeg,Phi	Si-N	SMD,VHF/UHF SATV, 20V, 50mA, 7,5GHz, Gp=10dB(2GHz)		44(EEBC)	SOT-143		BFG 197
BFG 67 R		Si-N	=BFG 67:		44(CBEE)	SOT-143R		-
BFG 67 X		Si-N	=BFG 67:		44s	SOT-143		-
BFG 67 XR		Si-N	=BFG 67:		44u	SOT-143R		-
BFG 71	Phi	Si						-
BFG 90 A	Phi	Si-N	UHF A, 20/15V, 25mA, 5GHz, Gp=19(800MHz)		24q	SOT-103		BFQ 28, BFR 49, BFR 90
BFG 91 A	Phi	Si-N	UHF A, 15/12V, 35mA, 6GHz, Gp=16,5dB(800MHz)		24q	SOT-103		BFQ 57, BFQ 58, BFQ 74
BFG 92 A	Aeg,Phi	Si-N	SMD, VHF/UHF A, 20/15V, 25mA, 5GHz, Gp=11dB(2GHz)		44(EEBC)	SOT-143		BFG 67, BFG 93A
BFG 92 AX		Si-N	=BFG 92:		44s	SOT-143		-
BFG 92(A)XR		Si-N	=BFG 92:		44u	SOT-143R		-
BFG 93 A	Aeg,Phi	Si-N	SMD, VHF/UHF A, 20V, 35...50mA, 6GHz, Gp=10dB(2GHz)		44(EEBC)	SOT-143		BFG 197
BFG 93 AX		Si-N	=BFG 93:		44s	SOT-143		-
BFG 93(A)XR		Si-N	=BFG 93:		44u	SOT-143R		-
BFG 94	Phi	Si-N	UHF A, 15/12V, 60mA, 6GHz, Gp=13,5dB(1GHz)	{BFG35	≈39°s	SOT-223		BFG 35
BFG 96	Phi	Si-N	UHF A, 20/15V, 150mA, 5GHz, Gp=15dB(800MHz)		24q	SOT-103		-
BFG 97	Phi	Si-N	VHF/UHF A, 20/15V, 0,1A, 5,5GHz, Gp=12dB(800MHz)		≈39°s	SOT-223		BFG 135
BFG 135(A)	Phi,Sie	Si-N	VHF/UHF A, 25/15V, 0,15A, 7GHz, Gp=12dB(800MHz)		≈39°s	SOT-223		-
BFG 193	Sie	Si-N	UHF A, 20/12V, 0,08A, 8GHz, Gp=16dB(800MHz)		≈39°s	SOT-223		-
BFG 194	Sie	Si-P	UHF A, 20/15V, 0,1A, 5GHz	{BFG19S	≈39°s	SOT-223		BFG 55, BFG 198
BFG 195	Phi	Si-N	VHF/UHF A, 20V, 0,1A, 0,5W, 7,5GHz, Gp=12dB(2GHz)		24q	SOT-103		2SC3358, 2SC3603
BFG 196	Sie	Si-N	UHF A, 20/12V, 0,1A, 7,2GHz, Gp=14dB(900MHz)		≈39°s	SOT-223		BFG 135
BFG 197	Phi	Si-N	SMD, UHF Widebd, 20V, 0,1A, 7,5GHz, Gp=10dB(2GHz)		44(EEBC)	SOT-143		-
BFG 197 X		Si-N	=BFG 197:		44s	SOT-143		-
BFG 197 XR		Si-N	=BFG 197:		44u	SOT-143R		-
BFG 198	Phi	Si-N	VHF/UHF A, 20/10V, 0,1A, 8GHz, Gp=15dB(800MHz)		≈39°s	SOT-223		-
BFG 235	Sie	Si-N	UHF A, 20/12V, 0,3A, 6GHz		≈39°s	SOT-223		-
BFG 505	Phi	Si-N	SMD, UHF SATV, 20V, 18mA, 9GHz, Gp=13dB(2GHz)		44(EEBC)	SOT-143		-
BFG 505 X		Si-N	=BFG 505:		44s	SOT-143		-
BFG 505 XR		Si-N	=BFG 505:		44u	SOT-143R		2SC4095
BFG 520	Phi	Si-N	SMD, UHF SATV, 20V, 70mA, 9GHz, Gp=13dB(2GHz)		44(EEBC)	SOT-143		-
BFG 520 X		Si-N	=BFG 520:		44s	SOT-143		-
BFG 520 XR		Si-N	=BFG 520:		44u	SOT-143R		-
BFG 540	Phi	Si-N	SMD, UHF SATV, 20V, 120mA, 9GHz, Gp=11dB(2GHz)		44(EEBC)	SOT-143		-
BFG 540 X		Si-N	=BFG 540:		44s	SOT-143		-
BFG 540 XR		Si-N	=BFG 540:		44u	SOT-143R		-
BFG 541	Phi	Si-N	SMD, UHF SATV, 20V, 120mA, 9GHz, Gp=9dB(2GHz)		≈39°s	SOT-223		-
BFJ								
BFJ 17	Riz	Si-N	VHF Drv, 60/40V, 1A, 0,8W, 400MHz		2a	TO-39		BFS 23, BFV 90, BFW 47, BFX 17
BFJ 18	Riz	Si-N	VHF A, 30/30V, 550MHz		5g	TO-72		BFS 62, BFW 41, BFX 18...19, BFX 31
BFJ 19	Riz	Si-N	VHF A, 30/30V, 550MHz		5g	TO-72		BFS 62, BFW 41, BFX 18...19, BFX 31
BFJ 21	Riz	Si-N	VHF, -/30V, 400MHz					-
BFJ 22	Riz	Si-P	VHF/UHF, -/35V, 700MHz					-
BFJ 22	Riz	Si-P	VHF/UHF, -/35V, 700MHz					-
BFJ 45	Riz	Si-N	HF/S, 80/35V, 1A, 0,8W, 120MHz		2a	TO-39		BSW 65...68, BSX 45...47, 2N3107...3110, ++
BFJ 46	Riz	Si-N	HF/S, 80/35V, 1A, 0,8W, 120MHz		2a	TO-39		BSW 65...68, BSX 45...47, 2N3107...3110, ++
BFJ 47	Riz	Si-N	HF/S, 120/80V, 1A, 0,8W, 120MHz		2a	TO-39		BSS 42...43, BSW 67...68, BSX 47, ++
BFJ 48	Riz	Si-N	HF/S, 120/80V, 1A, 0,8W, 120MHz		2a	TO-39		BSS 42...43, BSW 67...68, BSX 47, ++
BFJ 49	Riz	Si-N	HF/S, 120/64V, 1A, 0,8W, 150MHz		2a	TO-39		BSS 42...43, BSW 67...68, BSX 47, ++
BFJ 50	Riz	Si-N	HF/S, 120/64V, 1A, 0,8W, 150MHz		2a	TO-39		BSS 42...43, BSW 67...68, BSX 47, ++
BFJ 51	Riz	Si-P	LF,HF, -/35V, 0,8W, 60MHz		2a	TO-39		-
BFJ 52	Riz	Si-P	LF,HF, -/35V, 0,8W, 75MHz		2a	TO-39		-
BFJ 53	Riz	Si-P	LF,HF, -/64V, 0,8W, 120MHz		2a	TO-39		-
BFJ 54	Riz	Si-P	LF,HF, -/64V, 0,8W, 120MHzTO-39		2a	TO-39		-
BFJ 57	Riz	Si-N	LF,HF, 125/125V, 0,8W, 40MHz		2a	TO-39		BF 257...259, BF 657...659, 2N5058...5059
BFJ 64	Riz	Si-P	HF/S, 40/40V, 0,5A, 0,7W, 250MHz, <50/-ns		2a	TO-39		BSW 23, 2N3072...3073, 2N3467...3468, ++
BFJ 67	Riz	Si-N	40V, 0,36W		2a	TO-18		-
BFJ 68	Riz	Si-N	40V, 0,36W		2a	TO-18		-
BFJ 70	Riz	Si-N	HF Inp,Mx,Os,IF, 40/25V, 25mA, 550MHz		5g	TO-72		BF 199, BF 224, BF 311, 2SC2215...16,++
BFJ 72	Riz	Si-N	Uni, 45/45V, 0,1A, 0,5W, >50MHz, hFE=30...90		2a	TO-18		BC 167, BC 182, BC 237, BC 547, 2SD767++
BFJ 73	Riz	Si-N	=BFJ 72: hFE=76...333		2a	TO-18		BC 167, BC 182, BC 237, BC 547, ++
BFJ 74	Riz	Si-N	LF,HF, 70/50V, 0,3W, >250MHz		2a	TO-18		BC 174, BC 182, BC 190, BC 546, 2SC2240+
BFJ 75	Riz	Si-N	LF,HF, 40/25V, 0,3W, >300MHz		2a	TO-18		BC 167, BC 183, BC 237, BC 547, 2SD767++
BFJ 77	Riz	Si-N	VHF/UHF, 30/15V, >800MHz		5g	TO-72		BF 689, BF 763, 2N918, 2N2857, ++
BFJ 78	Riz	Si-N	VHF/UHF, 30/15V, 50mA, >600MHz		5g	TO-72		BF 689, BF 763, 2N918, 2N2857, ++
BFJ 79	Riz	Si-N	VHF/UHF, 25/13V, 50mA, >600MHz		5g	TO-72		BF 689, BF 763, 2N918, 2N2857, ++
BFJ 92	Riz	Si-N	LF, In, 50/45V, 0,1A, 0,3W, 45MHz, hFE=40...120		2a	TO-18		BC 184, BC 413...414, BC 550, 2SC2675,++
BFJ 93	Riz	Si-N	=BFJ 92: hFE=100...300		2a	TO-18		BC 184, BC 413...414, BC 550, 2SC2675,++
BFJ 98	Riz	Si-N	Vid, 150/150V, 0,1A, 0,8W, 90MHz		2a	TO-39		BF 257...259, BF 657...659, 2N5058...5059
BFN								
BFN		Z-Di	=SM 15T 68C (SMD-Marking)		71a(8x5mm)	SOD-15		›SM 15T....
BFN 16	Sie	Si-N	SMD, Vid, 250/250V, 0,2/0,5A, >60MHz	{BFN17	39b	SOT-89		2SC3554
BFN 17	Sie	Si-P	SMD, Vid, 250/250V, 0,2/0,5A, >60MHz	{BFN16	39b	SOT-89		-
BFN 18	Sie	Si-N	=BFN 16: 300/300V	{BFN19	39b	SOT-89		2SC3554
BFN 19	Sie	Si-P	=BFN 17: 300/300V	{BFN18	39b	SOT-89		-
BFN 20	Sie	Si-N	SMD, Vid, 300/300V, 20...50mA, >60MHz	{BFN21	39b	SOT-89		BF620, BFN18, 2SC3380, 2SC3515, 2SC4189
BFN 21	Sie	Si-P	SMD, Vid, 300/300V, 20...50mA, >60MHz	{BFN20	39b	SOT-89		BF 621, BFN 19, 2SA1384
BFN 22	Sgs,Sie	Si-N	SMD, Vid, 250/250V, 20/50A, >60MHz	{BFN23	35a	SOT-23		BF 820, BF 822, 2SC4412
BFN 22 R		Si-N	=BFN 22:		35d	SOT-23		-
BFN 23	Sgs,Sie	Si-P	SMD, Vid, 250/250V, 20/50A, >60MHz	{BFN22	35a	SOT-23		BF 821, BF 823, 2SA1682, 2SA1721
BFN 23 R		Si-N	=BFN 23:		35d	SOT-23		-
BFN 24	Sie	Si-N	=BFN 16:	{BFN25	35a	SOT-23		2SC4061, 2SC4497
BFN 25	Sie	Si-P	=BFN 17:	{BFN24	35a	SOT-23		2SA1721
BFN 26	Sie	Si-N	=BFN 18:	{BFN27	35a	SOT-23		2SC4061, 2SC4497
BFN 27	Sie	Si-P	=BFN 19:	{BFN26	35a	SOT-23		2SA1721
BFN 36	Sie	Si-N	=BFN 16: 1,5W	{BFN37	≈39°j	SOT-223		-
BFN 37	Sie	Si-P	=BFN 17: 1,5W	{BFN36	≈39°j	SOT-223		-
BFN 38	Sie	Si-N	=BFN 18: 1,5W	{BFN39	≈39°j	SOT-223		-
BFN 39	Sie	Si-P	=BFN 19: 1,5W	{BFN38	≈39°j	SOT-223		-

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
BFP								
BFP		Si-P	=2SB1308-P (SMD-Marking)		39	SOT-89		›2SB1308
BFP		Z-Di	=SM 15T 68CA(SMD-Marking)		71a(8x5mm)	SOD-15		›SM 15T....
BFP 10	Tho	Si-N	UHF A, 25V, 100mA, 0,35W, 4GHz, Gp=19,5dB(500MHz)		51r	SOT-173		BFG 96, BFP 96, BFR 96, BFQ 73
BFP 11	Tix	Si-N	S/Vid, 150/100V, 0,5A, 1,25W, 60MHz		7c	TO-92		BF 391...393, BFP 22, BFP 25, MPS-A42...43
BFP 12	Tix	Si-N	=BFP 11: 250/200V		7c	TO-92		BF 392...393, BFP 25, MPS-A42
BFP 13	Tix	Si-N	=BFP 11: 350/300V		7c	TO-92		MPS-A44...45, 2SD1350
BFP 14	Tix	Si-N	=BFP 11: 450/400V		7c	TO-92		MPS-A44, 2SD1350A
BFP 17	Sie	Si-N	=BFS 17P		44s	SOT-143		-
BFP 22	Sie	Si-N	Vid, 200/200V, 0,2/0,5A, 0,625W, >50MHz	{BFP23	7e	TO-92		BF 391...393, BF 422A, MPS-A42...43,++
BFP 23	Sie	Si-P	Vid, 200/200V, 0,2/0,5A, 0,625W, >50MHz	{BFP22	7e	TO-92		BF 491...493, BF 423A, MPS-A92...93,++
BFP 24	Sie							-
BFP 25	Sie	Si-N	=BFP 22: 300/300V	{BFP26	7e	TO-92		BF 393, BF 420A, MPS-A42
BFP 26	Sie	Si-P	=BFP 23: 300/300V	{BFP25	7e	TO-92		BF 493, BF 421A, MPS-A92
BFP 29	Sie	Si-N	=BFQ 29P:		44s	SOT-143		BFG 93A
BFP 35 A	Sie	Si-N	=BFR 34AP:		44s	SOT-143		BFG 93A
BFP 67	Aeg	Si-N	=BFG 67:		44s	SOT-143		-
BFP 81	Aeg,Sie	Si-N	=BFQ 81:		44s	SOT-143		-
BFP 90(A)	Phi,Tho	Si-N	UHF A, 20/15V, 30mA, 0,25W, 5GHz, Gp=19dB(800MHz)		51s	SOT-173		BFQ 69, BFQ 85, BFR 14, BFR 91, ++
BFP 91(A)	Phi,Tho	Si-N	UHF A, 15/12V, 50mA, 0,35W, 6GHz, Gp=18dB(800MHz)		51s	SOT-173		BFG 65, BFQ 65...66, 2SC3511, 2SC3062
BFP 92	Tho	Si-N	UHF A, 22V, 0,35W, 3,5GHz, Gp=22dB(500MHz)		51s	SOT-173		BFQ 59...60, BFQ 70...71, BFT 97, ++
BFP 92 A	Aeg	Si-N	=BFG 92A:		44s	SOT-143		-
BFP 93 A	Aeg,Sie	Si-N	=BFG 93A:		44s	SOT-143		-
BFP 96	Phi,Tho	Si-N	UHF A, 20V, 100mA, 0,5W, 4,5GHz, Gp=19dB(500MHz)		51s	SOT-173		BFG 96, BFQ 73, BFR 96
BFP 180	Sie	Si-N	=BFR 180:		44s	SOT-143		-
BFP 181	Sie	Si-N	=BFR 181:		44s	SOT-143		-
BFP 182	Sie	Si-N	=BFR 182:		44s	SOT-143		-
BFP 183	Sie	Si-N	=BFR 183:		44s	SOT-143		-
BFP 193	Sie	Si-N	=BFR 193:		44s	SOT-143		-
BFP 194	Sie	Si-P	=BFR 194:		44s	SOT-143		-
BFP 196	Sie	Si-N	SMD, UHF A, 20/12V, 0,1A, 8GHz, Gp=10,5dB(1750MHz)		44s	SOT-143		-
BFP 280	Sie	Si-N	=BFR 280:		44s	SOT-143		-
BFQ								
BFQ		Si-P	=2SB1308-Q (SMD-Marking)		39	SOT-89		›2SB1308
BFQ 10....16	Phi	N-FET	Dual In, 30V, 30mA, Idss=0,3...10mA,Ugs1-2 <5...50mV		TO-71	(SDG-SDG-)		2N3921...22, 2N3954...58, 2N5045...47
BFQ 17(P)	Mot,Phi,Sie	Si-N	SMD,VHF/UHF A,40V, 150mA, 1,2GHz, Gp=6,5dB(800MHz)		39b	SOT-89		BFQ 64
BFQ 18(A)	Mot,Phi,Sie	Si-N	SMD, UHF A, 30/25V, 150mA, 3,5GHz, F=8dB(200MHz) BFQ 18A: 25/15V, 3,6GHz		39b	SOT-89		BFQ 64
BFQ 19(P,S)	Mot,Phi,Sie	Si-N	SMD, UHF A, 20/15V, 75mA, 5GHz, Gp=9dB(800MHz) P: Gp=11,5dB(800MHz), S: Gp=11,8dB(800MHz)		39b	SOT-89		BFQ 193, 2SC3268, 2SC3607
BFQ 20...21	Tix	N-FET	Dual, 40V, Idss=0,3...1,5mA, Up<4V,Ugs1-2 <25...50mV		TO-71	(SDG-SDG-)		2N3954...58, 2N4082...85
BFQ 22(S)	Phi,Tho	Si-N	UHF A, 15/12V, 35mA, 5GHz, F=1,9dB/Gp=16dB(500MHz)		5g	TO-72		BFQ 69, BFQ 85, BFR 14, BFR 91, ++
BFQ 23	Phi,Sie	Si-P	UHF A, 15V, 35mA, 5GHz, F=2,4dB/Gp=6,5dB(500MHz)		24f	SOT-37		BFQ 56, BFQ 75...76
BFQ 23 C	Phi	Si-P	=BFQ 23:		51s	SOT-173		BFQ 56, BFQ 75...76
BFQ 24	Phi	Si-P	UHF A, 15V, 35mA, 5GHz, F=2,4dB/Gp=15dB(500MHz)		5g	TO-72		BFQ 24, BFQ 56, BFQ 75...76
BFQ 25...26	Tix	N-FET	Dual, 25V, Idss=10...40mA, Up<5V		TO-71	(SDG-SDG-)		2N5564...5566
BFQ 27	Tho	Si-N	UHF, In, 15/12V, 25mA, 0,2W, F<2,5dB(2GHz)		52	SOT-100		BFQ 69, BFQ 85, BFR 14, BFR 91, ++
BFQ 28	Sie	Si-N	UHF, In, 20/15V, 15mA, 5GHz, F=3dB/Gp=14dB(2GHz)		52r	SOT-100		BFG 90, BFQ 85, BFR 49, BFR 90...91, ++
BFQ 29(P)	Sie	Si-N	SMD, UHF, In, 20/15V, 30mA, 4GHz, F=2,1dB(800MHz) BFQ 29P: 4,7GHz, F=1,8dB(800MHz)		35a	SOT-23		BFR 92...93, BFT 75
BFQ 29 R		Si-N	=BFQ 29:		35d	SOT-23		BFR 92R...93R, BFT 75R
BFQ 30	Phi	Si-N	UHF, In, -/10V, 100mA, 0,25W, 2GHz		5g	TO-72		BFG 34, BFT 12, BFX 59
BFQ 31(A)	Fer,Tho	Si-N	SMD, VHF, 30/15V, 100mA, >600MHz, F<6dB(60MHz)		35a	SOT-23		BFR 106
BFQ 31(A)R		Si-N	=BFQ 31:		35d	SOT-23		-
BFQ 32	Phi,Sie	Si-P	UHF A,20/15V, 75mA, 4,2GHz, F=3,75/Gp=14dB(500MHz)		24f	SOT-37		BFQ 79, BFT 96, BFQ 194
BFQ 32 C		Si-P	=BFQ 32: 100mA, 4,5GHz		51s	SOT-173		BFQ 194
BFQ 32 S		Si-P	=BFQ 32: 100mA, 4,5GHz, Gp=17dB(500MHz)		24f	SOT-37		BFQ 194
BFQ 33	Phi	Si-N	UHF A, In, 9/7V, 20mA, 12GHz, F=3,8/Gp=7,4dB(4GHz)		52r	SOT-100		-
BFQ 33 C		Si-N	=BFQ 33:		51r	SOT-173		-
BFQ 34	Phi	Si-N	UHF A, 25/18V, 150mA, 4GHz, F=8/Gp=16,3dB(500MHz)		55r	SOT-122		BFQ 68
BFQ 34 T		Si-N	=BFQ 34: 3,7GHz, Gp=20dB(300MHz)		24f	SOT-37		BFG 34, BFG 96
BFQ 35	Tix	Si-P	Vid, 160/160V, 0,2A, 0,8W, >80MHz		2a	TO-39		BFT 44...45, 2SB606, 2SB622
BFQ 36	Tix	Si-P	=BFQ 35: 250/250V		2a	TO-39		BFT 44...45, 2SB606, 2SB622
BFQ 37	Tix	Si-P	=BFQ 35: 300/300V		2a	TO-39		BFT 44, 2SB622
BFQ 38	Phi	Si-N	S,Vid, 300/250V, 1A, 0,6W, >20MHz		2a	TO-39		BUX 55, BUY 59...60
BFQ 39	Phi	Si-N	=BFQ 38: 300/300V		2a	TO-39		BUX 55, BUY 59...60
BFQ 40	Phi	Si-N	=BFQ 38: 450/350V		2a	TO-39		BUX 55, BUY 59...60
BFQ 41	Aeg	Si-N	UHF Drv,Out, 50/25V, 350mA, 1GHz, PQ>0,45W(470MHz)		55r	SOT-48		BFR 65, MRF 626, 2N5944
BFQ 42	Phi	Si-N	VHF Drv,Out, 36/18V, 0,6/1,8A, PQ=2W(175MHz)		2a	TO-39		BFW 46, BLY 33, MRF 227, 2N3924, ++
BFQ 43(S)	Phi	Si-N	VHF Drv,Out, 36/18V, 1,25/3,75A, PQ=4W(175MHz)		2e(E=Case)	TO-39		(2N6255)[5]
BFQ 44...45	Tix	N-FET	Dual, 25V, Idss=10...40mA, Up<5V, Ugs1-2 <25...50mV		TO-71	(SDG-SDG-)		2N5564...5566
BFQ 46...48	Tix	N-FET	Dual, 30V, Idss=30...250µA, Up<4V, Ugs1-2 <10...50mV		TO-71	(SDG-SDG-)		2N3954...58, 2N4082...85
BFQ 49(A...C)	Tix	N-FET	Dual, 30V, Idss=0,3...5mA, Up<4V, Ugs1-2 <10...50mV		TO-71	(SDG-SDG-)		2N3921...22, 2N3954...58, 2N5045...47
BFQ 50	Phi	Si						
BFQ 51	Phi,Sie	Si-P	UHF A, 20/15V, 25mA, 5GHz, F=2,7/Gp=19dB(500MHz)		24f	SOT-37		BFT 95, BFQ 23, BFQ 56, BFQ 75...76
BFQ 51 C		Si-P	=BFQ 51: 30mA, Gp=21dB(500MHz)		51s	SOT-173		BFT 95, BFQ 23, BFQ 56, BFQ 75...76
BFQ 52	Phi	Si-P	UHF A, 20/15V, 25mA, 5GHz, F=2,7/Gp=17dB(500MHz)		5g	TO-72		BFT 95, BFQ 23...24, BFQ 56, BFQ 75...76
BFQ 53	Phi	Si-N	UHF A, 20/15V, 25mA, 5GHz, F=2,4/Gp=18dB(500MHz)		5g	TO-72		BFR 14, BFR 90...92, BFQ 22, BFQ 85
BFQ 54 T	Phi	Si-P	UHF-A, 25/18V, 150mA, 4,5GHz, Gp=18dB(300MHz)		24f	SOT-37		-
BFQ 56	Sie	Si-P	UHF A, In, 20/15V, 30mA, 5GHz, F=2/Gp=13dB(800MHz)		24f	SOT-37		BFQ 23, BFQ 75...76
BFQ 57	Sie	Si-N	UHF A, 25/16V, 35mA, 6,5GHz, Gp=10,5dB(4GHz)		52r	SOT-100		BFG 65, BFQ 65...66, BFQ 74
BFQ 58	Sie	Si-N	UHF A, In, 25/16V, 30mA, 6,5GHz, Gp=9dB(4GHz)		52r	SOT-100		BFG 65, BFQ 65...66, BFQ 74
BFQ 59	Sie	Si-N	UHF, In, 27/20V, 35mA, 4GHz, F=3,4/Gp=11dB(2GHz)		51r			BFT 97, BFQ 60, BFQ 70...71
BFQ 60	Sie	Si-N	UHF, In, 27/20V, 35mA, 4GHz, F=3,4/Gp=11dB(2GHz)		52r	SOT-100		BFT 97, BFQ 59, BFQ 70...71
BFQ 61	Sie	Si-P	SMD, UHF, In, -/15V, 30mA, 5GHz		35a	SOT-23		BFT 93
BFQ 62	Sie	Si-P	SMD, UHF, In, -/15V, 90mA, 5GHz		39b	SOT-89		2SC3357...58, 2SC4703
BFQ 63	Phi,Tho	Si-N	VHF/UHF A,In, 20V, 75mA, 4,5GHz, Gp=11,5dB(500MHz)		5g	TO-72		BFG 96, BFP 96, BFR 96, BFQ 73, ++
BFQ 64	Sie	Si-N	SMD, UHF A, 30/20V, 200mA, 3GHz, Gp=10dB(800MHz)		39b	SOT-89		-
BFQ 65	Aeg,Phi	Si-N	UHF A, In, 20/10V, 50mA, 7,5GHz, F=3/Gp=8dB(2GHz)		24f	SOT-37		BFG 65, BFQ 66, 2SC3062
BFQ 66	Phi	Si-N	UHF A, In, 20/10V, 50mA, 7,5GHz, F=3/Gp=12,5dB(2G)		51s	SOT-173		BFG 65, BFQ 65, 2SC3062
BFQ 67	Aeg,Phi	Si-N	SMD, UHF A, 20/10V, 0,05A, 8GHz, F=3/Gp=8dB(2GHz)		35a	SOT-23	2SC3356 35a	3SC3356, 2SC3445, 2SC3583, 2SC4592

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
BFQ 67 W		Si-N	=BFQ 67:		35a(2mm)	SOT-323		3SC4593
BFQ 68	Phi	Si-N	UHF A, 25/18V, 300mA, 4,5W, 4GHz, Gp=13dB(800MHz)		55r	SOT-122		-
BFQ 69	Sie	Si-N	UHF A, In, 25/15V, 30mA, 5,8GHz, F<1,4dB(800MHz)		24f	SOT-37		BFG 91, BFP 91, BFQ 57…58, BFQ 74, ++
BFQ 70	Sie	Si-N	UHF A, In, 20V, 30mA, 5GHz, F=1,5/Gp=18dB(800MHz)		51s	SOT-173		BFR 14, BFT 97, BFQ 59…60, BFQ 71, ++
BFQ 71	Sie	Si-N	UHF A, In, 20/15V, 30mA, 5,2GHz, F=3,2dB(2GHz)		51s	SOT-173		BFR 14, BFR 91, BFQ 69, BFQ 85, ++
BFQ 72	Sie	Si-N	UHF A,In, 20V, 50mA, 5,1GHz, F=2,5/Gp=18dB(800MHz)		51s	SOT-173		BFP 91, BFP 96, BFT 65, BFR 96
BFQ 73(S)	Sie	Si-N	UHF A, In, 20V, 90mA, 5GHz, F=4,5/Gp=9dB(800MHz) BFQ73S: 100mA, 5,3GHz, F=2,5/Gp=15dB(800MHz		51s	SOT-173		BFG 96, BFP 96, BFR 96
BFQ 74	Sie	Si-N	UHF A, In, 25/16V, 35mA, 6GHz, F=2,5dB(2GHz)		51s	SOT-173		BFG 65, BFQ 57…58, BFQ 65…66
BFQ 75	Sie	Si-P	UHF A, In, 15/12V, 50mA, 5GHz, F=3/Gp=14dB(800MHz)		51s	SOT-173		BFQ 23, BFQ 56, BFQ 76
BFQ 76	Sie	Si-P	UHF A, In, 20V, 30mA, 5GHz, F=2,5/Gp=17dB(800MHz)		51s	SOT-173		BFQ 23, BFQ 56, BFQ 75
BFQ 77	Sie	Si-N	UHF A, In, -/15V, 20mA, 7GHz, F<2/Gp=13dB(2GHz)		51s	SOT-173		BFG 65, BFQ 65…66, 2SC3586…87
BFQ 78	Sie	Si-P	UHF A, In, 25/20V, 50mA, 3,3GHz		51r			BFQ 32, 2SA1057…1058, 2SA1223
BFQ 79	Sie	Si-P	UHF A, In, -/15V, 75mA, 4,2GHz, F=3,75dB(500MHz)		51s	SOT-173		BFT 96, BFQ 32(S), 2SA1057, 2SA1223
BFQ 80	Sie	Si-N	UHF A, In, -/15V, 20mA, 7GHz, F<2dB(2GHz)		52r	SOT-100		BFG 65, BFQ 65…66, BFQ 77
BFQ 81	Aeg,Sie	Si-N	SMD, UHF A, In, 25V, 0,03A, 4,2GHz, F=2,5dB(2GHz)		35a	SOT-23		BFQ 29, BFR 93, BFT 75, 2SC3110
BFQ 82	Sie	Si-N	UHF A, 20/12V, 0,08A, 8GHz, F=2,3/Gp=11dB(2GHz)		51s	SOT-173		BFQ 196, 2SC3603
BFQ 85	Sgs	Si-N	UHF A, In, 20/15V, 40mA, 5GHz, F<3/Gp=15dB(1GHz)		25q	SOT-103		BFG 91, BFR 14, BFR 91, BFQ 69
BFQ 88	Sgs	Si-N	UHF A, In, 20/15V, 40mA, 5GHz, F<3/Gp=15dB(1GHz)		51r	SOT-173		BFG 91, BFP 91, 2SC3511
BFQ 88 A		Si-N	=BFQ 88: 80mA, F=2,5/Gp=14dB(1GHz)		51r	SOT-173		BFG 96, BFR 96, BFQ 73
BFQ 89	Sgs	Si-N	UHF A, In, 20/15V, 20mA, 6GHz, F=3dB(2GHz)		52r	SOT-100		BFG 91, BFQ 57…58, BFQ 74, BFQ 77
BFQ 98	Sgs	Si-P	UHF A, In, 20/15V, 40mA, 5GHz, F=2dB(1GHz)		52r	SOT-100		BFT 96, BFQ 23, BFQ 56, BFQ 75…76
BFQ 136	Phi	Si-N	UHF A, 25V, 0,6A, 9W(Tc=110°), 4GHz, Gp=12dB(800M)		55r	SOT-122		-
BFQ 149	Phi	Si-P	=BFQ 32: SMD		39b	SOT-89		-
BFQ 166	Phi	Si-N	Vid, hi-res, 20/20V, 0,5A, 2W, 1000MHz		≈39°s	SOT-223		-
BFQ 181	Sie	Si-N	UHF A, 20/12V, 20mA, 8GHz, F=1,8dB(1750MHz)		51s	SOT-173		BFQ 77
BFQ 182	Sie	Si-N	UHF A, 20V, 35mA, 8,3GHz, F=1,7/Gp=16dB(1750MHz)		51s	SOT-173		BFQ 66, BFQ 645
BFQ 193	Sie	Si-N	SMD, UHF A, 20/12V, 80mA, 7,5GHz, Gp=17dB(500MHz)		39b	SOT-89		2SC3301
BFQ 194	Sie	Si-P	=BFR 194:		51s	SOT-173		-
BFQ 196	Sie	Si-N	=BFR 196:		51s	SOT-173		-
BFQ 256	Phi	Si-P	Vid, hi-res, 100/65V, 0,3A, 2W, 1300MHz		≈39°s	SOT-223		-
BFQ 256 A	Phi	Si-P	=BFQ 256: 115/95V, 1200MHz		≈39°s	SOT-223		-
BFQ 645	Sie	Si-N	UHF A, 25/12V, 40mA, 9GHz, F<2,5/Gp=11dB(2GHz)		51s	SOT-173		2SC3587
BFR								
BFR		Si-P	=2SB1308-R (SMD-Marking)		39	SOT-89		›2SB1308
BFR		Si-N	=2SC4642K-R (SMD-Marking)		35	SOT-23		›2SC4642K
BFR		Si-N	=2SC4723-R (SMD-Marking)		35(2mm)	SOT-323		›2SC4723
BFR 10	Sgs	Si-N	HF,S, 75/40V, 0,5/1A, 0,8W, 350MHz, 14/80ns		2a	TO-39		BFX 96A…97A, BSS 27, 2N2218A…19A, ++
BFR 11	Sgs	Si-N	=BFR 10: 0,4W		2a	TO-18		BFX 94A…95A, BSW 63, 2N2221A…22A, ++
BFR 12	Aeg	Si-N	VHF/UHF Drv, 55V, 300mA, >480MHz, PQ>60mW(400MHz)		2a	TO-18		BLW 10, (BFX 55, 2N4428, 2SC2852, ++)[6]
BFR 14	Sie	Si-N	UHF A, In, 20/12V, 30mA, 3,6GHz, F<5dB(2GHz)		51s			BFT 97, BFQ 59…60, BFQ 70…71
BFR 14 A	Sie	Si-N	UHF A, In, 20/12V, 30mA, 5GHz, F<5dB(2GHz)		52r	≈SOT-100		BFG 91, BFR 91, BFQ 69, BFQ 85
BFR 14 B	Sie	Si-N	=BFR 14A: 6GHz, F<4dB(2GHz)		52r	SOT-100		BFG 91, BFQ 57…58, BFQ 74
BFR 14 C	Sie	Si-N	=BFR 14A: 27V, 35mA, 4,3GHz, F<4,5dB(2GHz)		51r			BFR 91, BFQ 69, BFQ 71, BFQ 85
BFR 15(A)	Sie	Si-N	UHF, In, 20V, 30mA, 3,3GHz, F=3/Gp=11,5dB(800MHz) BFR15A: 4,5GHz, F=2/Gp=12dB(800MHz)		5k	TO-72		BFS 55, BFT 66…67, BFQ 22, BFQ 63, ++
BFR 16	Sgs	Si-N	LF, In, 60/60V, 0,05A, 100MHz, hFE=150…490, F<4dB		2a	TO-18		BC 382, BC 414, BC 550, 2N2483…84, ++
BFR 17	Sgs	Si-N	=BFR 16: hFE=530>450		2a	TO-18		BC 382, BC 414, BC 550, 2N2483…84, ++
BFR 18	Sgs	Si-N	LF Drv, 85/55V, 0,5/1A, 0,5W, 90MHz		2a	TO-18		BC 639, BCX 24, 2N3700…01, 2SD774,++
BFR 19	Sgs	Si-N	LF Drv, 75/35V, 1A, 0,8W, 100MHz		2a	TO-39		BC 140…141, 2N1990, 2N2102, 2N2405, ++
BFR 20	Sgs	Si-N	LF Drv,S, 75/35V, 1A, 0,8W, 90MHz, 130/450ns		2a	TO-39		BC 140…141, BSX 59…61, 2N3444, ++
BFR 21	Sgs	Si-N	LF Drv,S, 120/70V, 1A, 0,8W, 90MHz, 130/450ns		2a	TO-39		BSS 42…43, BSW 67…68, BSX 47
BFR 22	Sgs	Si-N	LF,S, 120/65V, 1A, 1W, >120MHz		2a	TO-39		BSS 42…43, BSW 67…68, BSX 47, 2N2102
BFR 23	Sgs	Si-P	LF,S, 90/65V, 1A, 1W, >60MHz, <110/700ns (=2N4036)		2a	TO-39		BSW 40, 2N4036
BFR 24	Sgs	Si-P	LF,S, 60/40V, 1A, 1W, >60MHz, <110/700ns (=2N4037)		2a	TO-39		BSW 40, 2N4030…4033, 2N4036…4037
BFR 25	Sgs	Si-N	Nixie, 120/120V, 0,1A, 0,375W, >50MHz, <650/1300ns		2a	TO-18		BF 279…299, BSS 38, BSX 21, 2N4390,++
BFR 26	Tho	Si-N	VHF, 30/20V, 0,12A, 0,3W, >350MHz		2a	TO-18		BFX 59, (BFW 16…17)[6]
BFR 27	Tho	Si-N	Vid, 160V, 0,4A, 0,6W		2a	TO-5		2SD413, 2SD576, 2SD624
BFR 28	Sie	Si-N	VHF/UHF, 30/20V, 50mA, 1GHz, F<4,5dB(200MHz)		≈36e	(4,5mmØ)		BF 357, BF 377…378, BF 763, 2SC3037, ++
BFR 29	Phi	MOS-N-FET-d	LF,HF, 30V, Idss=10…40mA, Up<4V, F<5dB(200MHz)		5m	TO-72		3N142…143, 3N152, 3N154, 3N192…193
BFR 30	Mot,Phi	N-FET	SMD, Uni, 25V, Idss=4…10mA, Up<5V		35b	SOT-23		BF 512
BFR 31	Mot,Phi	N-FET	SMD, Uni, 25V, Idss=1…5mA, Up<2,5V		35b	SOT-23		BF 511, 2SK425
BFR 34(A)	Aeg,Sie	Si-N	UHF A, In, 20V, 30mA, 3,3GHz, F=5,5dB(2GHz) BFR 34A: 4,5GHz, F=4dB(2GHz), (=2N6620)		24f	SOT-37		BFT 97, BFQ 59…60, BFQ 70…71, 2N6620
BFR 35(A,AP)	Aeg,Sie	Si-N	=BFR 34: SMD, (=2N6619), BFR35AP: 4,9GHz		35a	SOT-23		BFR 92…93, BFT 75, BFQ 29, 2N6619
BFR 35(A)R		Si-N	=BFR 34: SMD		35d	SOT-23		BFR 92R…93R, BFT 75R, BFQ 29R
BFR 36(A)	Sgs,Tix	Si-N	VHF/UHF A,40V, 200mA, 0,8W, 1,3GHz, Gp=6,5dB(800M)		2a	TO-39		BFW 16…17, 2N4428, 2N5160
BFR 37	Sgs	Si-N	VHF/UHF A, 30V, 50mA, 1,4GHz, F=5/Gp=14dB(500MHz)		5k	TO-72		BFW 30, BFX 59, BFX 73, 2SC2570, 2SC3037
BFR 38	Sgs	Si-P	VHF/UHF, In, 40V, 20mA, 1GHz, F<6/Gp=13dB(800MHz)		5g	TO-72		BF 272, BF 316, BF 516, BF 606
BFR 39	Tix	Si-N	LF,S, 90/80V, 1A, 0,8W, >100MHz, <55/-ns		7c	TO-92	BC 639	7c BC 639, BFR 50, BFT 29, BFT 53, 2SC4488
BFR 40	Tix	Si-N	=BFR 39: 70/60V		7c	TO-92	BC 639	7c BC639, BFR50, BSS26, BSS40…41, 2SC3733+
BFR 41	Tix	Si-N	=BFR 39: 60/50V		7c	TO-92	BC 639	7c BC637, BFR51, BSS26, BSS40…41, 2SC3733+
BFR 44(A…C)	Tho	Si-N	Dual, VHF, 30/15V, 0,05A, >600MHz, F<6dB(60MHz)		TO-77	(CBE-EBC-)		2N3423…3424
BFR 45	Tix	N-FET	LF,HF, 30V, Idss=2…25mA, Up=0,5…8V		5k	TO-72		BFW 10…11, BFS 72, 2N3823
BFR 46	Fer	MOS-P-FET-e*	LF, In, 15V, 10mA, Idss<0,01mA, Up=2V		2b	TO-18		-
BFR 47	Fer	MOS-P-FET-e	=BFR 46: o.Gateschutz-D./without gate protection		2b	TO-18		-
BFR 48	Tho	Si-N	VHF, 50/30V, 100mA, 0,45W, >600MHz		2a	TO-39		BFR 36, BFW 16…17, BFX 55
BFR 49	Phi	Si-N	UHF, In, 20/15V, 25mA, 5GHz, F=4/Gp=10dB(2GHz)		52r	SOT-100		BFG 90, BFQ 28, BFQ 85, BFR 90…91, ++
BFR 50	Tix	Si-N	LF,S, 80/80V, 1A, 0,8W, >50MHz, <55/-ns		7c	TO-92		BC 639, BFR 39, BFT 29, BFT 53, 2SC3733
BFR 51	Tix	Si-N	=BFR 50: 60/60V		7c	TO-92		BC637, BFR40, BSS26, BSS40…41, 2SC3733+
BFR 52	Tix	Si-N	=BFR 50: 40/40V		7c	TO-92		BC637, BFR41, BSS26, BSS40…41, 2SC3733+
BFR 53	Phi,Tho	Si-N	SMD, UHF A, 18/10V, 50mA, 2GHz, Gp=10,5dB(800MHz)		35a	SOT-23		BFR 93, BFT 75, 2SC3014, 2SC3772…73,++
BFR 53 R		Si-N	=BFR 53:		35d	SOT-23		BFR 93R, BFT 75R
BFR 54	Phi	Si-N	VHF/UHF A, 40V, -/500mA, 500MHz, Gp=19dB(200MHz)		7a	TO-92		2SC2851, (BFX 55, 2SC2852)[6]
BFR 56	Tix	Si-N	LF,S, 60/40V, 1,2A, 1W		2a	TO-39		BC 140…141, BSW 65…68, BSX 45…47
BFR 57	Tix	Si-N	Vid, 160/160V, 0,2A, 1W, 100MHz		2a	TO-39		BF 257…259, BF 657…659, 2N5058…5059
BFR 58	Tix	Si-N	=BFR 57: 250/250V		2a	TO-39		BF 258…259, BF 658…659, 2N5058…5059
BFR 59	Tix	Si-N	=BFR 57: 300/300V		2a	TO-39		BF 259, BF 659, BFS 89, 2N5058
BFR 60	Tix	Si-P	LF,S, 80/80V, 1A, 0,8W, >50MHz, <55/-ns		7c	TO-92		BC 640, BFR 79, BFT 20, BFT 69, 2SA1708+
BFR 61	Tix	Si-P	=BFR 60: 60/60V		7c	TO-92		BC 638, BFR 80, 2N4026…4029, 2SA1708,++
BFR 62	Tix	Si-P	=BFR 60: 40/40V		7c	TO-92		BC 638, BFR 81, 2N4026…4029, 2SA1708,++
BFR 63	Phi	Si-N	VHF A,Drv, 40/25V, 200/500mA, PQ=0,15W(200MHz/20V)		55r	SOT-48		BFR 64…65, BFT 91, BLX 96

Original	Fabric.	Constr.	Info	(Compl.	Fig.		JAEGER	Fig.	International
BFR 64	Phi	Si-N	UHF A,Drv, 40/25V, 200/500mA, PQ=0,09W(800MHz/20V)		55r	SOT-48			BFT 91, BLX 96
BFR 65	Phi	Si-N	UHF A,Drv, 40/25V, 0,2/1A, PQ=0,45W(200MHz/20V)		55r	SOT-48			BFT 91, BLX 96
BFR 67(A,B)	Sgs	Si-N	Min, LF, 50/45V, 0,15A, F<10dB	(BFR69	(40b)				(BC 167, BC 182, BC 237, BC 547, ++)[6]
BFR 68(A...C)	Sgs	Si-N	=BFR 67: In, 30/20V, F<4dB	(BFR70	(40b)				(BC 169, BC 184, BC 239, BC 549, ++)[6]
BFR 69(VI,A,B)	Sgs	Si-P	Min, LF, 50/45V, 0,15A, F<10dB	(BFR67	(40b)				(BC 212, BC 257, BC 307, BC 557, ++)[6]
BFR 70(VI,A,B)	Sgs	Si-P	=BFR 69: In, 30/25V, F<4dB	(BFR68	(40b)				(BC 214, BC 259, BC 309, BC 559, ++)[6]
BFR 71	Sgs	Si-N	Min, LF, 85/55V, 0,2A, hFE=40...120	(BFR73	(40b)				(BC 546, 2SC2240, 2SC2675, 2SC3378,++)[6]
BFR 72	Sgs	Si-N	=BFR 71: hFE=100...300	(BFR74	(40b)				(BC 546, 2SC2240, 2SC2675, 2SC3378,++)[6]
BFR 73	Sgs	Si-P	Min, LF, 60/60V, 0,2A, hFE=40...120	(BFR71	(40b)				(BC 556, 2SA970, 2SA1137, 2SA1335,++)[6]
BFR 74	Sgs	Si-P	=BFR 73: hFE=100...300	(BFR72	(40b)				(BC 556, 2SA970, 2SA1137, 2SA1335,++)[6]
BFR 75	Sgs	Si-N	Min, VHF, -/25V, 10mA, 700MHz	(BFR76	(40b)				(BF 225, BF 314, BF 496, 2SC2215,++)[6]
BFR 76	Sgs	Si-P	Min, VHF, -/20V, 10mA, 450MHz	(BFR75	(40b)				(BF 324, BF 414, BF 506, BF 914, ++)[6]
BFR 77	Sgs	Si-N	LF,S, 120/80V, 1A, 0,8W, >50MHz		2a	TO-39			BSW 67...68, BSX 47, 2N3019...3020, ++
BFR 78	Sgs	Si-N	=BFR 77: 120/100V		2a	TO-39			BSW 67...68, BSX 47, 2N3019...3020, ++
BFR 79	Tix	Si-P	LF,S, 90/80V, 1A, 0,8W, >100MHz, <55/-ns		7c	TO-92	BC 640	7c	BC 640, BFR 60, BFT 20, BFT 69, 2SA1708+
BFR 80	Tix	Si-P	=BFR 79: 70/60V		7c	TO-92	BC 640	7c	BC 640, BFR 60, 2N4026...4029, 2SA1708,++
BFR 81	Tix	Si-P	=BFR 79: 60/50V		7c	TO-92	BC 640	7c	BC 638, BFR 61, 2N4026...4029, 2SA1708,++
BFR 83		Si-N	UHF, 40/25V, 0,2A, 1400MHz		55r	SOT-48			BFR 64...65
BFR 84	Phi	MOS-N-FET-d*	Dual-Gate, VHF, 20V, Idss=20...65mA, Up<3,8V		5h	TO-72	(BF 960)	25g	-
BFR 86(A,B)	Tix	Si-N	Vid, 120V, 0,2A, 0,8W, 130MHz		7c	TO-92	BF 420 A	7c	BFT 57...59, BF 391...393, BF 422A, ++
BFR 87(A,B)	Tix	Si-N	=BFR 86: 160/160V		7c	TO-92	BF 420 A	7c	BFT 57...59, BF 391...393, BF 422A, ++
BFR 88(A,B)	Tix	Si-N	=BFR 86: 250/250V		7c	TO-92	BF 420 A	7c	BFT 58...59, BF 392...393, BF 422A, ++
BFR 89(A,B)	Tix	Si-N	=BFR 86: 300/300V		7c	TO-92	BF 420 A	7c	BFT 59, BF 393, BF 420A, 2SC3468,++
BFR 90(A,B,H)	EUR	Si-N	UHF A, 20/15V, 25mA, 5GHz, F=2,4/Gp=19,5dB(500MHz) A: F=1,8/Gp=16dB(800MHz), B: F=2,2/Gp=13,5dB(1GHz) BFR 90H:		24f	SOT-37 =SOT-37	(2SC2570A)[4]	7f	BFG 90, BFQ 28, BFR 14, BFR 49, ++
BFR 91(A,H)	EUR	Si-N	UHF A, 15/12V, 35mA, 5GHz, F=1,9/Gp=18dB(500MHz) A: 6GHz, F=1,6/Gp=14dB(800MHz)BFR 91H:		24f	SOT-37 =SOT-37	(2SC2570A)[4]	7f	BFG 91, BFQ 69, BFQ 85, BFR 14
BFR 92(A,P)	EUR	Si-N	=BFR 90: SMD		35a	SOT-23			BFT 75, 2SC3011, 2SC3513, 2SC3161
BFR 92(A)R		Si-N	=BFR 90: SMD		35d	SOT-23			BFT 75R
BFR 92(A)W		Si-N	=BFR 90: SMD		35a(2mm)	SOT-323			-
BFR 93(A,P)	EUR	Si-N	=BFR 91: SMD		35a	SOT-23			BFT 75, 2SC3011, 2SC3513, 2SC3161
BFR 93(A)R		Si-N	=BFR 91: SMD		35d	SOT-23			BFT 75R
BFR 93(A)W		Si-N	=BFR 91: SMD		35a(2mm)	SOT-323			-
BFR 94	Phi	Si-N	UHF A, 30V, 0,15A, 3,5GHz, F=5/Gp=13,5dB(500MHz)		55r	SOT-48			BFQ 34, BFQ 68, BFT 98
BFR 95	Phi	Si-N	VHF/UHF A, 30V, 0,15A, 3,5GHz, F<10/Gp=9dB(200MHz)		2a	TO-39			(BFG 34, BFG 96)
BFR 96(H,S)	EUR	Si-N	UHF A, 20/15V, 75mA, 5GHz, F=3,3/Gp=15,2dB(500MHz) S: 100mA, 5,5GHz, F=2,9/Gp=11,5dB(800MHz) BFR 96H:		24f	SOT-37 =SOT-37			BFG 96, BFP 96, BFQ 73
BFR 97	Sgs	Si-N	VHF/UHF Drv,Out, 55/30V, 0,5A, PQ>1W(400MHz/28V)		2a	TO-39			2N3866, 2SC2852
BFR 98	Sgs	Si-N	VHF Drv,Out, 40/20V, 0,5A, PQ>1W(175MHz/12V)		2a	TO-39			BFQ 42, BFS 51, BLW 16, 2N4427, ++
BFR 99(A)	Mot,Sgs	Si-P	VHF/UHF Inp In, 25V, 50mA, 2GHz, F<5dB(800MHz) BFR 99A: 2,3GHz, Gp=10dB(800MHz)		5g	TO-72			BFT 96, BFQ 32, BFQ 78, 2SA1228
BFR 101 A	Phi	N-FET*	SMD, Uni, 30V, Idss=0,2...1,5mA, Up=0,2...1V		44(DSSubG)	SOT-143			-
BFR 101 B		N-FET*	=BFR 101A: Idss=1...5mA, Up=0,5...2,5V		44(DSSubG)	SOT-143			-
BFR 106	Phi,Sie	Si-N	SMD, VHF/UHF A, 20V, 0,1A, 5GHz, Gp=11,5dB(800MHz)		35a	SOT-23	2SC3356	35a	2SC3356, 2SC3775
BFR 134	Phi	Si-N	UHF A, 25/15V, 0,15A, 7GHz, Gp=12dB(800MHz)		24f	SOT-37			-
BFR 180	Sie	Si-N	SMD, UHF A,15V, 4mA, 4,4GHz, F=2,1/Gp=14dB(900MHz)		35a	SOT-23			-
BFR 180 W		Si-N	=BFR 180:		35a(2mm)	SOT-323			-
BFR 181	Sie	Si-N	SMD, UHF A, 20V, 20mA, 8GHz, F=2,2/Gp=12dB(1750M)		35a	SOT-23			BFR 505, 2SC3585
BFR 181 W		Si-N	=BFR 181:		35a(2mm)	SOT-323			BFS 505
BFR 182	Sie	Si-N	SMD, UHF A, 20V, 35mA, 8GHz, F=1,75/Gp=12dB(1750M)		35a	SOT-23			BFQ 67, 2SC3585
BFR 182 W		Si-N	=BFR 182:		35a(2mm)	SOT-323			-
BFR 183	Sie	Si-N	SMD, UHF A, 20V, 65mA, 8GHz		35a	SOT-23			BFR 193, BFR 520, 2SC3445
BFR 183 W		Si-N	=BFR 183:		35a(2mm)	SOT-323			BFS 520, 2SC4593
BFR 193	Sie	Si-N	SMD, UHF A, 20/12V, 0,08A, 8GHz, Gp=13,5dB(800MHz)		35a	SOT-23	2SC3356	35a	BFR 520, 2SC3356, 2SC3445
BFR 193 W		Si-N	=BFR 193:		35a(2mm)	SOT-323			BFS 520
BFR 194	Sie	Si-P	SMD, UHF A, 20/15V, 0,1A, 5GHz	(BFR106	35a	SOT-23			-
BFR 200	Phi	N-FET	SMD, asym., 30V, 20mA, Idss=0,2...3,5mA, Up=0,5...2V Io Igss<3pA(6V)		44(DSSubG)	SOT-143			-
BFR 280	Sie	Si-N	SMD, UHF A, 15/8V, 0,01A, 5GHz, F=2,4dB(1750MHz)		35a	SOT-23			BFR 92
BFR 280 W		Si-N	=BFR 280:		35a(2mm)	SOT-323			BFR 92W
BFR 505	Phi	Si-N	SMD, SATV, Wideband,20V, 18mA, 9GHz, Gp=10dB(2GHz)		35a	SOT-23			-
BFR 520	Phi	Si-N	SMD, SATV, Wideband, 20V, 70mA, 9GHz, Gp=9dB(2GHz)		35a	SOT-23			-
BFR 541	Phi	Si-N	=BFG 541:		25q	SOT-103			-
BFRC 96		Si-N	=BFR 96:		Chip				-
BFS									
BFS		Si-N	=2SC4642K-S (SMD-Marking)		35	SOT-23			=2SC4642K
BFS		Si-N	=2SC4723-S (SMD-Marking)		35(2mm)	SOT-323			=2SC4723
BFS 10	Sgs	Si-N	VHF A,Drv, 55/30V, 400mA, 0,5W, >500MHz		2a	TO-5			BFW 47, BFX 55, 2N3553
BFS 11	Sgs	Si-N	VHF Inp In, 45V, 50mA, 800MHz, F<4/Gp>19dB(200MHz)		5k	TO-72			BF 225, BF 314, BF 496, 2SC1856,++
BFS 12	Sgs	Si-P	LF Drv, 40/40V, 1A, 0,8W, >100MHz		2a	TO-39			BC 160...161, BCX 60, 2N4234...4236, ++
BFS 13 E	Sgs	Si-N	Min, LF, In, 40/40V, 0,05A, 90MHz	(BFS14	36c				BC 123
BFS 13 F		Si-N	=BFS 13E:		36f				BC 123
BFS 13 G		Si-N	=BFS 13E:		36e				BC 123
BFS 14 E	Sgs	Si-P	Min, LF, In, 40/40V, 0,05A, 40MHz	(BFS13	36c				BC 203
BFS 14 F		Si-P	=BFS 14E:		36f				BC 203
BFS 14 G		Si-P	=BFS 14E:		36e				BC 203
BFS 15 E	Sgs	Si-N	Min, LF,S, 40/30V, 0,05A, 400MHz	(BFS16	36c				(BC 123)
BFS 15 F		Si-N	=BFS 15E:		36f				(BC 123)
BFS 15 G		Si-N	=BFS 15E:		36e				(BC 123)
BFS 16 E	Sgs	Si-P	Min, LF,S, 40/30V, 0,05A, 210MHz	(BFS15	36c				(BC 203)
BFS 16 F		Si-P	=BFS 16E:		36f				(BC 203)
BFS 16 G		Si-P	=BFS 16E:		36e				(BC 203)
BFS 17(A,P,S)	EUR	Si-N	SMD, VHF/UHF, 25V, 25mA, 1GHz, Gp=11dB(800MHz) A: 2,8GHz, Gp=13dB(800MHz), P: F>5dB(800MHz)		35a	SOT-23	2SC3356	35a	2SC3005, 2SC3016, 2SC3161
BFS 17 R(AR)		Si-N	=BFS 17:		35d	SOT-23			-
BFS 17 W		Si-N	=BFS 17:		35a(2mm)	SOT-323			-
BFS 18	EUR	Si-N	SMD, HF, 30/20V, 30mA, 200MHz, F=4/Gp=26dB(100MHz)		35a	SOT-23			BF 554, BF 599, BF 799, BFS 20
BFS 18 R		Si-N	=BFS 18:		35d	SOT-23			BFS 20R
BFS 19	EUR	Si-N	SMD, HF, 30/20V, 30mA, 260MHz, F=4/Gp=28dB(100MHz)		35a	SOT-23			BF 554, BF 599, BF 799, BFS 20
BFS 19 R		Si-N	=BFS 19:		35d	SOT-23			BFS 20R
BFS 20	EUR	Si-N	SMD, HF, 30/20V 25mA, 450MHz, F=3/Gp=43dB(35MHz)		35a	SOT-23			BF 599, BF 799, BFS 17, 2SC3015, 2SC3374

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BFS 20 R		Si-N	=BFS 20:		35d	SOT-23			BFS 17R
BFS 21(A)	Phi	N-FET	Dual, 30V, 20mA, Idss>1mA, Up<6V, Ugs1-2 <10…20mV		2x 5k	2x TO-72			-
BFS 22(A,R)	Phi	Si-N	VHF Drv,Out, 36/18V, 0,75/2,25A, PQ=4W(175MHz/13V)		2a	TO-39			BFW 46, BFQ 43, MRF 237, 2N3924
BFS 22 Q		Si-N	=BFS 22:		55r	SOT-120			BLY 85, 2N5589
BFS 23(A,R)	Phi	Si-N	VHF Drv,Out, 65/36V, 0,5/1,5A, PQ=4W(175MHz/28V)		2a	TO-39			BFW 47, BLY 34, 2N3553
BFS 25 A	Phi	Si-N	SMD, UHF, Wideband, 8V, 6,5mA, 5GHz, Gp=13dB(1GHz)		35a(2mm)	SOT-323			BFS 505, BFR 92W, BF 280W
BFS 26 E	Sgs	Si-N	Min, HF,S, 20/20V, 0,05A, 550MHz, F=3,5dB(100MHz)		36c				-
BFS 26 F		Si-N	=BFS 26E:		36f				-
BFS 26 G		Si-N	=BFS 26E:		36e				-
BFS 27 E	Sgs	Si-P	Min, HF,S, 20/20V, 0,05A, 400MHz, F=6dB(100MHz)		36c				-
BFS 27 F		Si-P	=BFS 27:		36f				-
BFS 27 G		Si-P	=BFS 27:		36e				-
BFS 28(R)	Phi	MOS-N-FET-d	Dual-Gate, LF,HF, 20V, Up<5V, F<4/Gp=21dB(200MHz)		5h	TO-72			3N201…206, 3N209…213
BFS 29(P)	Tix	Si-N	Min, LF,S, 45/45V, 0,2A, 150MHz, F<10dB	{BFS32					-
BFS 30(P)	Tix	Si-N	Min, LF,S, 45/45V, 0,2A, 150MHz, F<10dB	{BFS33					-
BFS 31(P)	Tix	Si-N	Min, LF,S, 45/30V, 0,2A, 150MHz, F<10dB	{BFS34					-
BFS 32(P)	Tix	Si-P	Min, LF,S, 45/45V, 0,2A, 200MHz, F<3dB	{BFS29					-
BFS 33(P)	Tix	Si-P	Min, LF,S, 45/45V, 0,2A, 200MHz, F<3dB	{BFS30					-
BFS 34(P)	Tix	Si-P	Min, LF,S, 45/30V, 0,2A, 200MHz, F<4dB	{BFS31					-
BFS 36	Fer	Si-N	SMD, LF, In, 45/45V, 0,5A, >30MHz	{BFS37	35d(2mm)	SOT-323			(BC 817R, BCW 65R…66R, BCX 19R,++)[6]
BFS 36 A		Si-N	=BFS 36: 30/30V		35d(2mm)	SOT-323			(BC 818R, BCW 65R…66R, BCX 20R,++)[6]
BFS 37	Fer	Si-P	SMD, LF, In, 45/45V, 0,5A, >30MHz	{BFS36	35d(2mm)	SOT-323			(BC 807R, BCW 67R…68R, BCX 17R,++)[6]
BFS 37 A		Si-P	=BFS 37: 30/30V		35d(2mm)	SOT-323			(BC 808R, BCW 67R…68R, BCX 18R,++)[6]
BFS 38	Fer	Si-N	SMD, LF,HF, 45/45V, 0,5A, >150MHz	{BFS40	35d(2mm)	SOT-323			(BC 817R, BCW 65R…66R, BCX 19R,++)[6]
BFS 38 A		Si-N	=BFS 38: 25/25V		35d(2mm)	SOT-323			(BC 818R, BCW 65R…66R, BCX 20R,++)[6]
BFS 39	Fer	Si-N	=BFS 38: 60/45V	{BFS41	35d(2mm)	SOT-323			(BCW 65R…66R, BCX 41R)[6]
BFS 40	Fer	Si-P	SMD, LF,HF, 45/35V, 0,5A, >150MHz	{BFS38	35d(2mm)	SOT-323			(BC 807R, BCW 67R…68R, BCX 17R,++)[6]
BFS 40 A		Si-P	=BFS 40: 25/25V		35d(2mm)	SOT-323			(BC 808R, BCW 67R…68R, BCX 18R,++)[6]
BFS 41	Fer	Si-P	=BFS 40: 60/45V	{BFS39	35d(2mm)	SOT-323			(BCW 68R, BCX 42R)[6]
BFS 42	Fer	Si-N	SMD, LF,HF, 60/30V, 1A, >60MHz	{BFS44	35d(2mm)	SOT-323			(BCW 65R…66R, BCX 41R)[6]
BFS 43	Fer	Si-N	=BFS 42: 60/60V	{BFS45	35d(2mm)	SOT-323			(BCW 65R…66R, BCX 41R)[6]
BFS 44	Fer	Si-P	SMD, LF,HF, 60/30V, 1A, >60MHz	{BFS42	35d(2mm)	SOT-323			(BCW 68R, BCX 42R)[6]
BFS 45	Fer	Si-P	=BFS 44: 60/60V	{BFS43	35d(2mm)	SOT-323			(BCW 68R, BCX 42R)[6]
BFS 46(A)	Fer	Si-N	#MD, VHF, 30/15V, 0,5A, >600MHz, Gp=15dB(200MHz)		35d(2mm)	SOT-323			-
BFS 50	Aeg	Si-N	VHF/UHF Drv,Out, 36/18V, 0,4A, PQ>1W(400MHz/12V)		2a	TO-39			MRF 629, 2N3948
BFS 51	Aeg	Si-N	VHF Os,Drv, 40/20V, 0,75A, PQ=1W(175MHz/12V)		2a	TO-39			BFQ 42, BFR 98, BLW 16, BLY 61, ++
BFS 55	Sie	Si-N	UHF A, 20/12V, 50mA, 3,3GHz, F=5/Gp=10dB(800MHz)		5k	TO-72			BFQ 63, BFQ 72, BFT 65
BFS 55 A		Si-N	=BFS 55: 20/15V, 4,5GHz, F=2,9/Gp=12dB(800MHz)		5k	TO-72			BFQ 63, BFQ 72, BFT 65
BFS 57(P)	Tix	Si-N	Min, UHF, 25/15V, 50mA, 1700MHz						-
BFS 58(P)	Tix	Si-N	Min, UHF, 25/15V, 50mA, 2400MHz						-
BFS 59(K,L,M)	Fer	Si-N	LF,HF, 60/30V, -/1A, 0,5W, >150MHz, hFE>40	{BFS96	40e	≈TO-92	BC 639	7c	BC 637, BSS 26, BSS 40…41, 2N2221…22++
BFS 60(K,L,M)	Fer	Si-N	=BFS 59: 60/40V, hFE=100…300	{BFS97	40e	≈TO-92	BC 639	7c	BC 637, BSS 26, BSS 40…41, 2N2221…22++
BFS 61(K,L,M)	Fer	Si-N	=BFS 59: 80/60V	{BFS98	40e	≈TO-92	BC 639	7c	BC 639, 2N2221A…22A, 2SC4488
BFS 62	Aeg	Si-N	VHF, 40/25V, 25mA, >580MHz, F<4dB(200MHz)		5k	TO-92			BF 225, BF 314, BF 496, 2SC1856,++
BFS 64	Tho	Si-N	VHF/UHF A, 30/15V, 50mA, 0,4W		51r				BFW 93
BFS 65	Tho	Si-N	VHF/UHF A,Drv, 40/20V, 200mA, 0,4W		51r				-
BFS 67(P)	Tix	N-FET	Min, 50V, Idss=0,5…10mA, Up<6V						-
BFS 68(P)	Tix	N-FET	Min, 30V, Idss=4…25mA, Up<8V						-
BFS 69	Aeg	Si-P	Min, LF,HF, 30/25V, 0,1A, >50MHz, F<10dB(1kHz)		36c	(TOM-13)			BC 202…203
BFS 70	Tix	N-FET	Uni, VHF, 50V, Idss=0,5…2,5mA, Up<4		5k	TO-72			=2N3821
BFS 71	Tix	N-FET	Uni, VHF, 50V, Idss=2…10mA, Up<6V		5k	TO-72			=2N3822
BFS 72	Tix	N-FET	VHF, In, 30V, Idss=4…20mA, Up<8V, F<2,6dB(100MHz)		5k	TO-72			=2N3823
BFS 73	Tix	N-FET	Chopper, sym, 50V, on<250Ω		5k	TO-72			=2N3824
BFS 74	Tix	N-FET	Chopper, sym, 40V, Idss>50mA, Up-4…10V, <9/25ns		2b	TO-18			=2N4856, BSV 78
BFS 75	Tix	N-FET	Chopper, sym, 40V, Idss=20…100mA, Up<6V, <10/50ns		2b	TO-18			=2N4857, BSV 79
BFS 76	Tix	N-FET	Chopper, sym, 40V, Idss=8…80mA, Up<4V, <20/100ns		2b	TO-18			=2N4858, BSV 80
BFS 77	Tix	N-FET	=BFS 74: 30V		2b	TO-18			=2N4859, BSV 78
BFS 78	Tix	N-FET	=BFS 75: 30V		2b	TO-18			=2N4860, BSV 79
BFS 79	Tix	N-FET	=BFS 76: 30V		2b	TO-18			=2N4861, BSV 80
BFS 80	Tix	N-FET	VHF In,30V, Idss=5…15mA, Up<6V, F<4/Gp>10dB(400M)		5k	TO-72			=2N5245, BFW 11, 2N5245
BFS 85	Fer	Si-N	SMD, UHF, In, 25/12V, 25mA, >1GHz, F<6dB(500MHz		35d(2mm)	SOT-323			(BFS 17R)[6]
BFS 86	Aeg	Si-N	VHF/UHF A, 50V, 0,3A, >1GHz, PQ>90mW(800MHz/28V)						-
BFS 87	Aeg	Si-N	VHF/UHF A, 50/30V, 0,3A, 1,1GHz						-
BFS 88	Fer	Si-N	SMD, UHF, In, 30/15V, 25mA, >1GHz, F<5dB(500MHz)		35d(2mm)	SOT-323			(BFS 17R)[6]
BFS 89	Sgs,Tix	Si-N	Vid, 300/300V, 0,15/0,5A, 0,58W, 90MHz		2a	TO-39	BF 259	2a	BF 259, BF 659, BFR 59, 2N5058
BFS 90(A,B)	Tix	Si-P	LF,S, 140/140V, 0,1A, 0,8W		2a	TO-39			BFW 44, 2N3634…3637
BFS 91(A,B)	Tix	Si-P	=BFS 90: 80/80V		2a	TO-39			BSV 17, 2N3634…3637
BFS 92	Phi,Tix	Si-P	LF,S, 100/60V, 1A, 0,8W, >40MHz, <55/-ns		2a	TO-39			BCX 60, BSS 17, BSW 40, 2N3634…3637, ++
BFS 93	Phi,Tix	Si-P	=BFS 92		2a	TO-39			BCX 60, BSS 17, BSW 40, 2N3634…3637, ++
BFS 94	Phi,Tix	Si-P	=BFS 92: 80/40V		2a	TO-39			BCX 60, BSS 17, BSW 40, 2N3634…3637, ++
BFS 95	Phi,Tix	Si-P	=BFS 92: 40/35V		2a	TO-39			BCX 60, BSS 18, BSW 40, 2N3634…3637, ++
BFS 96(K,L,M)	Fer	Si-P	LF,HF, 60/30V, -/1A, 0,5W, >150MHz, hFE>40	{BFS59	40e	≈TO-92	BC 640	7c	BC 638, BSW 24, 2N2906(A)…2907(A), ++
BFS 97(K,L,M)	Fer	Si-P	=BFS 96: 60/40V, hFE=100…300	{BFS60	40e	≈TO-92	BC 640	7c	BC 638, BSW 24, 2N2906(A)…2907(A), ++
BFS 98(K,L,M)	Fer	Si-P	=BFS 96: 80/60V	{BFS61	40e		BC 640	7c	BC 640, 2N4027…4029, 2SA1708
BFS 99	Sgs	Si-N	Nixie Drv, 120/90V, 0,05A, 0,3W		2a	TO-18			BF 297…299, BSS 38, BSX 21, 2SC3378,++
BFS 505	Phi	Si-N	=BFG 505:		35a(2mm)	SOT-323			-
BFS 520	Phi	Si-N	=BFG 520:		35a(2mm)	SOT-323			-
BFS 540	Phi	Si-N	=BFG 540:		35a(2mm)	SOT-323			-
BFT….BFU									
BFT 10(A….C)	Tix	N-FET	S,VHF, 40V, Idss=10…70mA, Up=2…7V, F=1,4dB(100M)		7f	SOT-30			BF 256, BF 348, 2N5397, 2N5486
BFT 11	Tix	P-FET	S, VHF, 25V, Idss>10mA, Up=4…9,5V		7f	SOT-30			2N4343
BFT 12	Sie	Si-N	UHF A,Os, 25/15V, 150mA, 2GHz, Gp=8dB(800MHz)		24f	SOT-37			BFG 34, BFG 96, (BFW 16, BFR 95)[6]
BFT 13	Tho	Si-N	UHF A, 25/20V, 20mA, 0,3W, 4GHz, F=3dB(1GHz)		24f				BFG 90, BFQ 28, BFR 49, BFR 90
BFT 13 A,B		Si-N	=BFT 13: 0,15W		52r	SOT-100			BFG 90, BFQ 28, BFR 49, BFR 90
BFT 14	Tho	Si-N	UHF A,Drv, 25/20V, 60mA, 0,7W, 4GHz		24f				BFP 96, BFQ 72…73, BFR 96, BFT 65
BFT 14 A,B		Si-N	=BFT 14: 0,3W		52r	SOT-100			BFP 96, BFQ 72…73, BFR 96, BFT 65
BFT 15	Tho	Si-N	UHF A,Drv, 25/20V, 150mA, 0,8W, 3GHz		24f				BFG 34, BFG 96
BFT 16	Tho	Si-N	UHF A,Drv, 25/20V, 200mA, 0,7W, 3GHz		24f				(BFG 34, BFG 96)
BFT 17	Tho	Si-N	UHF, 30/15V, 50mA, >1,8GHz, F=5dB(500MHz)		5g	TO-72			BFQ 63, BFS 55
BFT 18	Tho	Si-N	UHF A,Drv, 25/20V, 50mA, 0,7W, 4GHz		24f				BFQ 72…73, BFT 65
BFT 18 A		Si-N	=BFT 18: 0,3W		52r	SOT-100			BFQ 72…73, BFT 65
BFT 19	Rca	Si-P	S,Vid, 200/150V, 1A, 1W, >25MHz		2a	TO-39			BFT 28A…C, MJ 5415…5416, 2N5415…5416

Original	Fabric.	Constr.	Info	(Compl.	Fig.		JAEGER	Fig.	International
BFT 19 A		Si-P	=BFT 19: 300/250V		2a	TO-39			BFT 28C, MJ 5415…5416, 2N5416
BFT 19 B		Si-P	=BFT 19: 400/350V		2a	TO-39			MJ 5416
BFT 20	Tix	Si-P	LF,S, 80/35V, 1A, 0,36W, >60MHz, <55/-ns	(BFT53	2a	TO-18	BC 640	7c	BC 640, BFT 69, 2N4027, 2N4029, 2SA1708+
BFT 21	Tix	Si-P	=BFT 20: 60/30V	(BFT54	2a	TO-18	BC 640	7c	BC 638, BFT 70, 2N4026…4029, 2SA1705,++
BFT 22	Tix	Si-P	=BFT 20: 40/20V	(BFT55	2a	TO-18	BC 640	7c	BC 638, BFT 71, 2N4026…4029, 2SA1705,++
BFT 23	Aeg	Si-N	VHF, 25V, >600MHz, hFE>100						-
BFT 24	Phi	Si-N	UHF A, 8/5V, 2,5mA, 2,3GHz, F=3,8/Gp=17dB(500MHz)		24f	SOT-37			BFQ 59…60, BFQ 70, BFR 34, BFT 97
BFT 25	Phi	Si-N	SMD,UHF A,8/5V, 6,5mA, 2,3GHz, F=3,8/Gp=18dB(500M)		35a	SOT-23			BFQ 29, BFR 35, BFR 53, 2SC3099
BFT 25 A		Si-N	=BFT 25: 5GHz, F<2,5/Gp=15dB(1GHz)		35a	SOT-23			BFR 92…93, 2SC3110
BFT 25 R		Si-N	=BFT 25:		35d	SOT-23			BFQ 29R, BFR 35R, BFR 53R, 2SC3089
BFT 26	Phi	Si-N	=4x BFW 93						-
BFT 27	Fer	Si-N	SMD, LF, 60/60V, 0,5A, >30MHz, F<4dB(1kHz)		35d(2mm)	SOT-323			(BCW 65R…66R, BCX 41R)[6]
BFT 28	Rca	Si-P	S/Vid, 150/100V, 1A, 1W, >25MHz		2a	TO-39			BFT 19(A,B), 2N5415…5416, MJ 5415…5416
BFT 28 A		Si-P	=BFT 28: 200/150V		2a	TO-39			BFT 19(A,B), 2N5415…5416, MJ 5415…5416
BFT 28 B		Si-P	=BFT 28: 250/200V		2a	TO-39			BFT 19A…B, 2N5416, MJ 5415…5416
BFT 28 C		Si-P	=BFT 28: 300/250V		2a	TO-39			BFT 19A…B, 2N5416, MJ 5415…5416
BFT 29	Tix	Si-N	LF,S, 90/80V, 1A, 0,36W, >100MHz,	(BFT69	2a	TO-18	BC 639	7c	BC 639, BFR 39, BFR 50, BFT 53, 2SC4488+
BFT 30	Tix	Si-N	=BFT 29: 70/60V	(BFT70	2a	TO-18	BC 639	7c	BC639, BFR50, BSS26, BSS40…41, 2SC4488+
BFT 31	Tix	Si-N	=BFT 29: 60/50V	(BFT71	2a	TO-18	BC 639	7c	BC639, BFR51, BSS26, BSS40…41, 2SC4485+
BFT 32	Tix	Si-N	LF Drv,Out, 80/60V, 5A, 1W, >100MHz	(BFT35	2a	TO-39			BSS 45, BUX 34, BUY 80, 2N5336…5339
BFT 33	Tix	Si-N	=BFT 32: 100/80V	(BFT36	2a	TO-39			BUX 34, BUY 80, 2N5338…5339
BFT 34	Tix	Si-N	=BFT 32: 120/100V	(BFT37	2a	TO-39			BUX 34, BUY 80, 2N4895…4897
BFT 35	Tix	Si-P	LF Drv,Out, 80/60V, 5A, 1W, >100MHz	(BFT32	2a	TO-39			BSS 46, BUY 90, 2N6190…6191
BFT 36	Tix	Si-P	=BFT 35: 100/80V	(BFT33	2a	TO-39			BUY 90, 2N6192…6193
BFT 37	Tix	Si-P	=BFT 35: 120/100V	(BFT34	2a	TO-39			BUY 90
BFT 38	Sie	Si-P	UHF, -/12V, 35mA, 4800MHz, F=3/Gp=11dB(800MHz)		5g	TO-72			BFQ 24
BFT 39	Tix	Si-N	LF,S, 90/80V, 1A, 0,8W, >100MHz	(BFT79	2a	TO-39	BC 141	2a	BC 141, BSW 39, BSS 42…43, BSX 46…47++
BFT 40	Tix	Si-N	=BFT 39: 70/60V	(BFT80	2a	TO-39	BC 141	2a	BC 140…141, BSW 39, BSX 45…47, ++
BFT 41	Tix	Si-N	=BFT 39: 60/50V	(BFT81	2a	TO-39	BC 141	2a	BC 140…141, BSW 39, BSX 45…47, ++
BFT 42	Tix	Si-N	LF Drv, 125/110V, 1A, 0,8W, >50MHz		2a	TO-39			BSS 42…43, BSW 67…68, BSX 47, ++
BFT 43	Tix	Si-N	=BFT 42: 125/100V		2a	TO-39			BSS 42…43, BSW 67…68, BSX 47, ++
BFT 44	Phi	Si-P	S/Vid, 300/300V, 0,5A, 0,75W, 70MHz, 125/125ns		2a	TO-39			BFT 19A…B, MJ 5415…5416, 2N5416, ++
BFT 45	Phi	Si-P	=BFT 44: 250/250V		2a	TO-39			BFT 19A…B, MJ 5415…5416, 2N5416, ++
BFT 46	Phi	N-FET	SMD, LF,HF In, 25V, Idss=0,2…1,5mA, Up<1,2V		35b	SOT-23			-
BFT 47	Tho	Si-N	Vid, 160/160V, 0,2A, 0,8W, 110MHz		2a	TO-39	BF 259	2a	BF 257…259, BFR 57…59, 2N5058…5059
BFT 48	Tho	Si-N	=BFT 47: 250/250V		2a	TO-39	BF 259	2a	BF 258…259, BFR 58…59, 2N5058…5059
BFT 49	Tho	Si-N	=BFT 47: 300/300V		2a	TO-39	BF 259	2a	BF 259, BFR 59, BFS 89, 2N5058
BFT 50	Tho	Si-N	UHF, In, -/22V, 0,25W, 3,5GHz, F<2,5dB(500MHz)		5g	TO-72			BFR 15, BFS 55, BFT 66…67, BFW 99, ++
BFT 51	Phi	Si-N	UHF A,Drv, 35V, 0,4A, >3GHz, F<9,5dB(800MHz)		2a	TO-39			-
BFT 53	Tix	Si-N	LF,S, 80/35V, 1A, 0,36W, >50MHz, <55/-ns	(BFT20	2a	TO-18	BC 639	7c	BC 639, BFR 39, BFR 50, BFT 29, 2SC4488+
BFT 54	Tix	Si-N	=BFT 53: 60/30V	(BFT21	2a	TO-18	BC 639	7c	BC637, BFT30, BSS26, BSS40…41, 2SC4485+
BFT 55	Tix	Si-N	=BFT 53: 40/20V	(BFT22	2a	TO-18	BC 639	7c	BC637, BFT30, BSS26, BSS40…41, 2SC4485+
BFT 57	Tix	Si-N	Vid, 160/160V, 0,2A, 0,36W, 110MHz		2a	TO-18	BF 420 A	7c	BF 391…393, BFR 87…89, BF 422A, ++
BFT 58	Tix	Si-N	=BFT 57: 250/250V		2a	TO-18	BF 420 A	7c	BF 392…393, BFR 88…89, BF 422A, ++
BFT 59	Tix	Si-N	=BFT 57: 300/300V		2a	TO-18	BF 420 A	7c	BF 393, BFR 89, BF 420A, 2SC3468,++
BFT 60	Tix	Si-P	LF,S, 80/35V, 1A, 0,8W, >60MHz, <55/-ns		2a	TO-39	(BC 161)[7]	2a	BCX 60, BSW 40, 2N4031, 2N4033, ++
BFT 61	Tix	Si-P	=BFT 60: 60/30V		2a	TO-39	BC 161	2a	BC 161, BSW 40, 2N4030…4033, ++
BFT 62	Tix	Si-P	=BFT 60: 40/20V		2a	TO-39	BC 161	2a	BC 160…161, BSW 40, 2N4030…4033, ++
BFT 65	Sie	Si-N	UHF A, In, 20V, 50mA, 5GHz, F=2,8/Gp=12dB(800MHz)		24f	SOT-37			BFP 96, BFQ 72…73, BFR 96, 2SC3511,++
BFT 66	Sie	Si-N	UHF A, In, 20/15V, 30mA, 4GHz, F=1,9dB(800MHz)		5k	TO-72			BFQ 22, BFQ 63
BFT 66 S(E)	Sgs	Si-N	=BFT 66: 25/18V, F=1,5dB(500MHz)		5g	TO-72			BFQ 22, BFQ 63
BFT 67	Sie	Si-N	=BFT 66: F=2,3dB(800MHz)		5k	TO-72			BFQ 22, BFQ 63
BFT 69	Tix	Si-P	LF,S, 90/80V, 1A, 0,36W, >100MHz	(BFT29	2a	TO-18	BC 640	7c	BC 640, BFR 60, BFR 79, BFT 20, 2SA1708+
BFT 70	Tix	Si-P	=BFT 69: 70/60V	(BFT30	2a	TO-18	BC 640	7c	BC 640, BFT 20, 2N4027, 2N4029, 2SA1708+
BFT 71	Tix	Si-P	=BFT 69: 60/50V	(BFT31	2a	TO-18	BC 640	7c	BC 638, BFT 21, 2N4026…4029, 2SA1705,++
BFT 72	Tho	Si-N	Vid P, 160/160V, 0,1A, 60MHz		14h	TO-126	BF 459	14h	BF 457…459, BF 415, BF 417, 2SC3502,++
BFT 73	Tho	Si-N	=BFT 72: 250/250V		14h	TO-126	BF 459	14h	BF 458…459, BF 415, BF 417, 2SC3503,++
BFT 74	Tho	Si-N	=BFT 72: 300/300V		14h	TO-126	BF 459	14h	BF 459, BF 417, 2SC3417, 2SC3503,++
BFT 75	Sie	Si-N	SMD, UHF A, In, 20V, 50mA, 4,6GHz, F=2,8dB(800MHz)		35a	SOT-23	2SC3356	35a	BFR 93, 2SC3161, 2SC3513, 2SC3704,++
BFT 75 R		Si-N	=BFT 75:		35d	SOT-23			BFR 93R
BFT 79	Tix	Si-P	LF,S, 90/80V, 1A, 0,8W, >100MHz	(BFT39	2a	TO-39	(BC 161)[7]	2a	BCX 60, BSW 40, 2N4036
BFT 80	Tix	Si-P	=BFT 79: 70/60V	(BFT40	2a	TO-39	BC 161	2a	BCX 60, BSW 40, 2N4031, 2N4033, 2N4036
BFT 81	Tix	Si-P	=BFT 79: 60/50V	(BFT41	2a	TO-39	BC 161	2a	BC 161, BSW 40, 2N4030…33, 2N4036…37++
BFT 82	Tix	Si-N	LF,S, 90/75V, 2A, 0,8W, >100MHz	(BFT85	7c	TO-92			2SC4489, 2SD1642, 2SD2182
BFT 83	Tix	Si-N	=BFT 82: 70/60V	(BFT86	7c	TO-92			MPS 651, 2SC3328, 2SC3669, 2SD1642,++
BFT 84	Tix	Si-N	=BFT 82: 60/50V	(BFT87	7c	TO-92			MPS 650…651, 2SC3328, 2SD1207, 2SD1835+
BFT 85	Tix	Si-P	LF,S, 90/75V, 2A, 0,8W, >100MHz	(BFT82	7c	TO-92			2SA1709, 2SB1438
BFT 86	Tix	Si-P	=BFT 85: 70/60V	(BFT83	7c	TO-92			MPS 751, 2SA1315, 2SA1429, 2SB1438,++
BFT 87	Tix	Si-P	=BFT 85: 60/50V	(BFT84	7c	TO-92			MPS 750…751, 2SA1315, 2SA1706, 2SB1438+
BFT 91	Aeg	Si-N	UHF Drv,Out, 60/30V, 350mA, PQ>1,5W(470MHz/28V)		55r	SOT-48			BLW 89, BLW 92, BLY 76
BFT 92	Phi,Sie	Si-P	SMD, UHF A, 20V, 25mA, 5GHz, F=2,7/Gp=18dB(500MHz)		35a	SOT-23			BF 770A, BFR 182, 2SC3011, 2SC3513
BFT 92 R		Si-P	=BFT 92:		35d	SOT-23			-
BFT 92 W		Si-P	=BFT 92:		35a(2mm)	SOT-323			BFR 182W
BFT 93	Phi,Sie	Si-P	SMD, UHF A, 15V, 35mA, 5GHz, F=2,4/Gp=16,5dB(500M)		35a	SOT-23			BF 770A, BFR 182, 2SC3011, 2SC3513
BFT 93 R		Si-P	=BFT 93:		35d	SOT-23			-
BFT 93 W		Si-P	=BFT 93:		35a(2mm)	SOT-323			BFR 182W
BFT 95(A,B,H)	Aeg,Sgs	Si-P	UHF A, 15V, 25mA, 5GHz, F=2/Gp=12dB(1GHz) BFT 95A: 3,6GHz, B: 20V, H: -		24f	≈SOT-37			BFQ 23, BFQ 51, BFQ 56, BFQ 75…76
BFT 96(A)	Aeg,Sgs	Si-P	UHF A, 20V, 75mA, 4,5GHz, F=4/Gp=10dB(800MHz) BFT 96A: 3,6GHz, F=4,5dB(1GHz)		24f	≈SOT-37			BFQ 32S, BFQ 54T, BFQ 194
BFT 97	Sie	Si-N	UHF Inp In, 20V, 30mA, 5GHz, F=2,1dB(800MHz)		24f	SOT-37			BFQ 59…60, BFQ 70…71, BFR 14, BFR 91++
BFT 98	Sie	Si-N	UHF A, 30/20V, 200mA, 3,3GHz, Gp=15dB(800MHz)		55r	TO-117			BFQ 68
BFT 98 B		Si-N	=BFT 98:		51r	TO-131			-
BFT 98 T		Si-N	=BFT 98: 150mA, 3,2GHz, Gp=12dB(800MHz)		24f	SOT-37			BFG 34
BFT 99	Sie	Si-N	UHF A, 30V, 350mA, 3,3GHz, Gp=12dB(800MHz)		55r	TO-117			(BFQ 68)
BFT 99 A	Sie	Si-N	=BFT 99:		51r	TO-131			-
BFU 308	Phi	N-FET	Sym, VHF/UHF, 25V, Idss=12…60mA, Up=1…6,5V		2b	TO-18			BF 256C, 2N5397, 2N5486
BFU 309	Phi	N-FET	=BFU 308: Idss=12…30mA, Up=1…4V		2b	TO-18			-
BFU 310	Phi	N-FET	=BFU 308: Idss=24…60mA, Up=2…6,5V		2b	TO-18			-

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
BFV								
BFV 10	Tix	Si-N	Min, HF,S, 50/30V, 0,8A, >200MHz		Chip			BFV 50
BFV 11	Tix	Si-N	Min, HF,S, 50/30V, 0,8A, >200MHz		Chip			BFV 50
BFV 12	Tix	Si-N	Min, HF,S, 50/35V, 0,8A, >250MHz		Chip			BFV 51
BFV 13	Tix	Si-P	Min, Dual, 60/50V, 0,05A, F<4dB(1kHz)		Chip			BFV 15
BFV 14	Tix	Si-N	Min, LF Drv, 60/40V, 1A, >50MHz		Chip			BFV 16
BFV 15	Tix	Si-P	Min, Dual, 60/60V, 0,05A, F<4dB(1kHz)		Chip			BFV 13
BFV 16	Tix	Si-N	Min, LF Drv, 100V, 1A		Chip			-
BFV 17	Tix	Si-N	Min, LF, 80/60V, >60MHz		Chip			-
BFV 18	Tix	Si-N	Min, LF, 80/60V, >150MHz		Chip			-
BFV 19	Tix	Si-N	Min, LF,HF, 60/60V, 0,03A, F<4dB(1kHz)		Chip			BFV 62
BFV 20	Tix	Si-P	Min, LF,S, 40/30V, 0,6A, >150MHz, hFE=40…120		Chip			-
BFV 21	Tix	Si-P	=BFV 20: hFE=100…400		Chip			-
BFV 22	Tix	Si-P	=BFV 20: 50/50V, hFE=100…300		Chip			-
BFV 23	Tix	Si-P	S, 12/12V, 0,2A, 0,36W, >400MHz, <60/-ns, hFE>40		2a	TO-46		BSV 21, BSW 25, BSW 37, BSX 29, ++
BFV 24	Tix	Si-P	=BFV 23: hFE=30…120		2a	TO-46		BSV 21, BSW 25, BSW 37, BSX 29, ++
BFV 25	Tix	Si-P	Min, LF In, 60/45V, 0,03A, >30MHz, hFE=30…120		Chip			-
BFV 26	Tix	Si-P	=BFV 25: hFE=100…400		Chip			-
BFV 27	Tix	Si-N	Min, SS, 15/6V, 0,05A, >500MHz, <15/-ns		Chip			BFV 39, BFV 42, BFV 47…48
BFV 28	Tix	Si-N	Min, SS, 15/6V, 0,05A, >500MHz, <12/-ns		Chip			BFV 39, BFV 42, BFV 47…48
BFV 29	Tix	Si-P	Min, S, 20/15V, 0,2A, >400MHz, <35/-ns		Chip			-
BFV 30	Tix	Si-P	Min, S, 20/15V, 0,1A, >140MHz, <60/-ns		Chip			-
BFV 31	Tix	Si-P	Min,S, 12/12V, 0,2A, >350MHz, <60/-ns, hFE=30…150		Chip			BFV 29
BFV 32	Tix	Si-P	=BFV 31: hFE=20…200		Chip			BFV 29
BFV 33	Tix	Si-P	Min, LF,HF, 25/20V, 0,05A, >140MHz		Chip			BFV 20…22
BFV 34	Tix	Si-P	Min, Chopper, sym, 15/10/15V, 0,1A, >10MHz, hFE>80		Chip			-
BFV 35	Tix	Si-P	=BFV 34: 25/20/25V, hFE>40		Chip			-
BFV 36	Tix	Si-P	=BFV 34: 40/35/40V, hFE>30		Chip			-
BFV 37	Tix	Si-N	Min, Chopper, 30/30/15V, 0,1A, >20MHz		Chip			-
BFV 38	Tix	Si-N	=BFV 37: 45/45/18V		Chip			-
BFV 39	Tix	Si-N	Min, SS, 40/15V, 0,2A, >500MHz, <12/-ns		Chip			BFV 42…44, BFV 48
BFV 40	Tix	Si-N	Min, S, 25/18V, 0,2A, >200MHz, <40/-ns		Chip			BFV 49
BFV 41	Tix	Si-N	Min, S, 20/12V, 0,2A, >250MHz, <45/-ns		Chip			BFV 39, BFV 42…44, BFV 47…48
BFV 42	Tix	Si-N	Min, SS, 35/15V, 0,2A, >400MHz, <12/-ns		Chip			BFV 39, BFV 43…44, BFV 47…48
BFV 43	Tix	Si-N	Min, SS, 30/15V, 0,2A, >300MHz, <20/-ns		Chip			BFV 39, BFV 42, BFV 47…48
BFV 44	Tix	Si-N	Min, SS, 30/15V, 0,2A, >300MHz, <20/-ns		Chip			BFV 39, BFV 42, BFV 47…48
BFV 45	Tix	Si-N	Min, S, 35/15V, >250MHz		Chip			-
BFV 46	Tix	Si-N	Min, S, 35/15V, >300MHz		Chip			-
BFV 47	Tix	Si-N	Min, SS, 30/12V, 0,2A, >400MHz, <15/-ns		Chip			BFV 39, BFV 42…44
BFV 48	Tix	Si-N	Min, SS, 30/15V, 0,2A, >400MHz, <12/-ns		Chip			BFV 39, BFV 42…44
BFV 49	Tix	Si-N	Min, S, 25/15V, 0,2A, >200MHz, <40/-ns		Chip			BFV 40
BFV 50	Tix	Si-N	Min, S, 50V, 0,8A, >175MHz, <65/-ns		Chip			BFV 51…55
BFV 51	Tix	Si-N	Min, S, 60/30V, 0,8A, <40/-ns		Chip			BFV 53…55
BFV 52	Tix	Si-N	Min, S, 50/30V, 1A, >175MHz, <45/-ns		Chip			BFV 50…51, BFV 53…55
BFV 53	Tix	Si-N	Min, S, 60/30V, 0,8A, <40/-ns		Chip			BFV 51, BFV 54, BFV 55
BFV 54	Tix	Si-N	Min, S, 60/30V, >250MHz, <40/-ns		Chip			BFV 51, BFV 53, BFV 55
BFV 55	Tix	Si-N	Min, S, 75/40V, 0,5A, >175MHz, <40/-ns		Chip			-
BFV 56	Tix	Si-N	HF/S, 60/30V, 1A, 0,5W, >200MHz, <40/-ns		2a	TO-46		BSS 26, BSS 40…41, 2N4014
BFV 56 A		Si-N	=BFV 56: 75/40V, >175MHz		2a	TO-46		2N4014
BFV 57	Tix	Si-N	HF/S, 50/30V, 0,5A, 0,8W, >300MHz, <35/-ns		2a	TO-46		BSX 48…49, BSV 59, 2N4013…4014, ++
BFV 57 A		Si-N	=BFV 57: 80/50V		2a	TO-46		2N4013…4014
BFV 58	Tix	Si-N	Min, VHF, 60/25V, 500mA, >150MHz		Chip			BFV 12
BFV 59	Tix	Si-N	Min, VHF/UHF, 25/13V, 50mA, >600MHz, F=3,5dB(200M)		Chip			-
BFV 60	Tix	Si-N	Min, LF In, 30/30V, 0,03A, >30MHz, hFE=20…150		Chip			-
BFV 61	Tix	Si-N	=BFV 60: hFE=80…300		Chip			-
BFV 62	Tix	Si-N	Min, LF In, 60/50V, 0,05A, >45MHz, F<3dB(1kHz)		Chip			-
BFV 63	Tix	Si-N	HF/S, 60/30V, 0,8A, 0,5W, >250MHz, 25/200ns		2a	TO-46		BSS 26, BSS 40…41, 2N2221…2222
BFV 63 A		Si-N	=BFV 63: 75/40V, >300MHz		2a	TO-46		BSW 63…64, 2N2221A…2222A
BFV 63 B		Si-N	=BFV 63: >350MHz, 25/175ns		2a	TO-46		BSS 26, BSS 40…41, 2N2221…2222
BFV 64(A,B)	Tix	Si-P	HF/S,60/40V, 0,6A, 0,4W, >200MHz, 26/70ns, hFE>100 BFV 64A: 60/60V, B: hFE=40…120		2a	TO-46		BSW 24, 2N2906…2907, 2N4026…4029
BFV 65	Tix	Si-N	HF/S, 40/20V, 0,3A, 0,36W, >300MHz, <40/40ns		2a	TO-46		BSS 10, BSX 26, BSX 39, 2N3261
BFV 65 A,B		Si-N	=BFV 65: 40/40V, >500MHz, <12/15ns		2a	TO-46		BSS 10, BSX 26, BSX 39, 2N3261
BFV 66(A)	Tix	Si-N	HF/S, 60/40V, 0,8A, 0,5W, >250MHz, <40/-ns		2a	TO-46		BSS 26, BSS 40…41, 2N2221…2222
BFV 67	Tix	Si-N	SS, 15/6V, 0,05A, 0,3W, >600MHz, <15/-ns		2a	TO-46		BSV 89…92, BSX 27, BSX 44, 2N2475, ++
BFV 68	Tix	Si-N	LF In, 45/45V, 0,05A, 0,36W, >30MHz, F<3dB(1kHz)		2a	TO-46		BC 382…384, BC 413…414, BC 550
BFV 68 A		Si-N	=BFV 68: 60/60V, F<2dB(1kHz)		2a	TO-46		2N2483…2484, 2N3117, 2SC2390, ++
BFV 69	Tix	Si-N	VHF/UHF, 30/15V, 50mA, 0,2W, >600MHz, F<6dB(60MHz)		2a	TO-46		BF 180…183, BF 689, BF 763, 2N2857, ++
BFV 69 A		Si-N	=BFV 69: 25V		2a			BF 180…183, BF 689, BF 763, 2N2857, ++
BFV 70	Tix	Si-N/P	SMD, 2x NPN + 2x PNP, 60/40V, >200MHz, <45/-ns		14-FLP	TO-84/85		-
BFV 70 N		Si-N/P	=BFV 70:		14-DIP	TO-116		-
BFV 71	Tix	Si-N/P	SMD, 2x NPN + 2x PNP, 60/40V, >200MHz, <45/-ns		14-FLP	TO-84/85		-
BFV 71 N		Si-N/P	=BFV 71:		14-DIP	TO-116		-
BFV 72	Tix	Si-N	SMD, 3x NPN, 40/15V, 0,5A, <15/-ns		14-FLP	TO-84/85		-
BFV 72 N		Si-N	=BFV 72:		14-DIP	TO-116		-
BFV 73	Tix	Si-N/P	2x NPN + 2x PNP, 50/30V, 0,8A, >250MHz		14-FLP	TO-84/85		-
BFV 73 N		Si-N/P	=BFV 73:		14-DIP	TO-116		-
BFV 75	Tix	Si-N	SMD, 4x NPN, Chopper, 30/25V, 0,1A		10-FLP	TO-89		-
BFV 75 N		Si-N	=BFV 75:		10-DIP			-
BFV 76	Tix	Si-N	SMD, 4x NPN, Chopper, 30/15V, 0,1A, >20MHz		10-FLP	TO-89		-
BFV 76 N		Si-N	=BFV 76:		10-DIP			-
BFV 77	Tix	Si-P	SMD, 4x PNP, 40/15V, 0,2A, >350MHz, <15/-ns		10-FLP	TO-89		-
BFV 77 N		Si-P	=BFV 77:		10-DIP			-
BFV 78	Tix	Si-N	SMD, 4x NPN, 40/15V, 0,2A, >350MHz		10-FLP	TO-89		-
BFV 78 N		Si-N	=BFV 78:		10-DIP			-
BFV 79	Tix	Si-N	SMD, 4x NPN, 40/15V, 0,2A, >350MHz		14-FLP	TO-84/85		-
BFV 79 N		Si-N	=BFV 79:		14-DIP	TO-116		-
BFV 80	Tix	Si-N	Min, VHF/UHF, 25/12V, 50mA, >500MHz, F=3dB(60MHz)		Chip			BFV 59
BFV 81	Mot,Tix	Si-P	HF/S, 12/12V, 0,2A, 0,3W, >400MHz, <60/-ns		24b	TO-50		(BSV 21, BSW 25, BSW 37, BSX 29, ++)[6]
BFV 81 A,B		Si-P	=BFV 81: 20/15V		24b	TO-50		(2N3209, 2N3905…3906, 2N4125…4126)[6]
BFV 82(A….C)	Mot,Tix	Si-P	LF,S, 25/20V, 50…100mA, 0,3W, >140MHz		24b	TO-50		(2N3905…3906, 2N4125…4126)[6]
BFV 83(A….C)	Mot,Tix	Si-N	S, 40/15…20V, 0,2A, 0,3W, >300…350MHz, <40/-ns		24b	TO-50		(BSW 41, BSY 63, 2N708, 2N4123)[6]

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
BFV 84(A,B)	Mot,Tix	Si-N	VHF/UHF, 25…30V, 50mA, >600…800MHz		24b	TO-50		BF 362…363, (BF 377…378, BF 763)[6]
BFV 85(B)	Mot,Tix	Si-N	HF/S, 60/30V, 0,8A, 0,36W, >250MHz, F<4dB(1kHz)		24b	TO-50		(BSS 26, BSS 40…41, 2N2221…2222)[6]
BFV 85 A,C		Si-N	=BFV 85(B): 75/40V		24b	TO-50		(BSW 63…64, 2N2221A…2222A)[6]
BFV 85 D,E		Si-N	LF In, 45/45V, 0,03A, 0,3W, >30MHz, F<4dB(1kHz)		24b	TO-50		(BC 382…384, BC 413…414, BC 550)[6]
BFV 85 F,G		Si-N	LF In, 60/60V, 0,05A, 0,3W, >30MHz, F<3…4dB(1kHz)		24b	TO-50		(2N2483…2484, 2N3117, 2SC2390, ++)[6]
BFV 86(A….C)	Mot,Tix	Si-P	LF,S, 60/40…60V, 0,6A, 0,36W, >200MHz, <45/-ns		24b	TO-50		(BSW 24, 2N2906…2907, 2N4026…4029)[6]
BFV 87(A,B)	Mot,Tix	Si-N	SS, 40/15V, 0,2A, 0,3W, >500MHz, <12/-ns		24b	TO-50		(BSS 11, BSX 19…20, 2N2369)[6]
BFV 88(A….D)	Mot,Tix	Si-N	HF/S, 60/30V, 0,8A, 0,36W, >250MHz		24b	TO-50		(BSS 26, BSS 40…41, 2N2221…2222)[6]
BFV 89	Mot,Tix	Si-N	Chopper, 30/30/15V, 0,1A, 0,3W, >20MHz		24b	TO-50		-
BFV 89 A		Si-N	=BFV 89: 45/45/18V		24b	TO-50		-
BFV 90(A,B)	Tix	Si-N	HF Drv, 70/50V, 0,8…1A, 0,8W, >300MHz		2a	TO-5		BFX 17, BFX 96…97
BFV 91	Tix	Si-P	4x PNP, 12/12V, 0,2A, >400MHz, <60/-ns		14-FLP	TO-84/85		-
BFV 91 N		Si-P	=BFV 91:		14-DIP	TO-116		-
BFV 92	Tix	Si-N	4x NPN, 40/15V, 0,2A, >350MHz, <20/-ns		14-FLP	TO-84/85		-
BFV 92 N		Si-N	=BFV 92:		14-DIP	TO-116		-
BFV 93	Tix	Si-N	SMD, 4x NPN, 50/30V, 0,8A, >250MHz		10-FLP	TO-89		-
BFV 93 A		Si-P	=BFV 93: PNP		10-FLP	TO-89		-
BFV 93 AN		Si-P	=BFV 93N: PNP		14-DIP	TO-116		-
BFV 93 N		Si-N	=BFV 93:		14-DIP	TO-116		-
BFV 94	Tix	Si-N	SMD, 4x NPN, 50/30V, 0,8A, >250MHz		14-FLP	TO-84/85		-
BFV 94 N		Si-N	=BFV 94:		14-DIP	TO-116		-
BFV 95	Tix	Si-P	SMD, 4x PNP, 50/30V, 0,8A, >250MHz		14-FLP	TO-84/85		-
BFV 95 N		Si-P	=BFV 95:		14-DIP	TO-116		-
BFV 96	Tix	Si-N	SMD, 4x NPN, 40/25V, 0,8A, >175MHz		14-FLP	TO-84/85		-
BFV 96 N		Si-N	=BFV 96:		14-DIP	TO-116		-
BFV 97	Tix	Si-N	SMD, 4x NPN, 30/15V, 0,05A, >600MHz		14-FLP	TO-84/85		-
BFV 97 N		Si-N	=BFV 97:		14-DIP	TO-116		-
BFV 98	Tix	Si-N	SMD, 4x NPN, 45/45V, 0,03A, >30MHz		14-FLP	TO-84/85		-
BFV 98 N		Si-N	=BFV 98:		14-DIP	TO-116		-
BFV 99	Tix	Si-N	LF,S, 75/55V, 1A, 0,5W		2a	TO-46		BC 639, BSW 63…64, 2N2221A…2222A, ++
BFVP 20	Ucp	Si-N	SMD, 40V, -/0,2A, 150 MHz		Chip	TO-122		-
BFW								
BFW		Z-Di	=SM 15T 100C(SMD-Marking)		71a(8x5mm)	SOD-15		=SM 15T….
BFW 10	Mot,Phi,Tix	N-FET	VHF A,sym, 30V, Idss=8…20mA, Up<8V, F<2,5dB(100M)		5k	TO-72		BFS 72, 2N3823
BFW 11	Mot,Phi,Tix	N-FET	=BFW 10: Idss=4…10mA, Up<6V		5k	TO-72		BFS 71, 2N3822
BFW 12	Mot,Phi	N-FET	LF,HF In, 30V, Idss=1…5mA, Up<2,5V		5k	TO-72		(2N4340)
BFW 13	Mot,Phi	N-FET	LF,HF In, 30V, Idss=0,2…1,5mA, U<1,2V		5k	TO-72		(2N4338)
BFW 16(A)	Phi,Sie,++	Si-N	VHF/UHF A,40/25V, 150mA, 1200MHz, PQ=0,15W(200MHz)		2a	TO-39		BFR 36, BLW 11
BFW 17(A)	Phi,Sie,++	Si-N	=BFW 16: 1100MHz		2a	TO-39		BFR 36, BLW 11
BFW 19	Sgs	Si-N	VHF Drv, 40/20V, 0,3A, >500MHz		2a	TO-39		BFS 50, BFX 33, BFX 55, 2N3137T
BFW 20	Mot,Sgs,Tix	Si-P	LF In, 60/60V, 0,2A, 0,36W, >40MHz, F<3dB, hFE>100		2a	TO-18		=2N3962, 2SA970, 2SA1136…37, 2SA1335,++
BFW 21	Mot,Sgs,Tix	Si-P	=BFW 20: 80/80V		2a	TO-18		=2N3963, 2SA970, 2SA1136…37, 2SA1335
BFW 22	Mot,Sgs,Tix	Si-P	=BFW 20: 45/45V, hFE=250…600		2a	TO-18		BC 214, BC 415…416, BC 560, =2N3964,++
BFW 23	Mot,Sgs,Tix	Si-P	=BFW 20: hFE=250…600		2a	TO-18		=2N3965, 2SA970, 2SA1133…37, 2SA1335,++
BFW 24	Mot,Sgs	Si-N	LF,S, 100/60V, 1A, 0,8W, >60MHz, F<7dB, (=2N3108)		2a	TO-39		BC 141, BSX 46…47, 2N3107…3108, ++
BFW 25	Mot,Sgs	Si-N	=BFW 24: 80/40V, >70MHz, (=2N3109)		2a	TO-39		BC 140…141, BSX 45…47, 2N3107…3110,++
BFW 26	Mot,Sgs	Si-N	=BFW 24: 80/40V, (=2N3110)		2a	TO-39		BC 140…141, BSX 45…47, 2N3107…3110,++
BFW 27	Aeg	MOS-P-FET-e	S, 30V, 25mA, Up=2,5…6V, on=500Ω		5(GDSSub)	TO-72		-
BFW 29	Tho,Tix	Si-N	LF,S, 50/30V, 0,4A, 0,6W, >40MHz		2a	TO-5		BC 140…141, BC 302, 2N1613, 2N1711, ++
BFW 30	Phi,Sie,++	Si-N	VHF/UHF A, 20/10V, 50mA, 1,6GHz, F<7dB(500MHz)		5g	TO-72	2SC2570A	7f BFR 37, BFX 59, BFX 73
BFW 31	Mot,Tix	Si-P	Uni, 50/30V, 0,7A, 0,5W, 200MHz	{BFW32	2a	TO-18		BC 327, BC 638, 2N2906…07, 2SA1705,++
BFW 32	Mot,Tix	Si-N	Uni, 50/30V, 0,7A, 0,5W, 200MHz	{BFW31	2a	TO-18		BC 337, BC 637, 2N2221…22, 2SC4485,++
BFW 33	Mot,Sgs	Si-N	Uni, 120/80V, 1A, 0,8W, >50MHz		2a	TO-5		BSS 42…43, BSV 84, BSX 47, =2N1893, ++
BFW 34	Tho	Si-N	LF,S, 50/30V, 0,2A, 0,6W, >70MHz, hFE>40		2a	TO-5		BC 140…141, BSX 45…47, =2N4432, ++
BFW 35	Tho	Si-N	=BFW 34: hFE=80…150		2a	TO-5		BC 140…141, BSX 45…47, =2N5203, ++
BFW 36	Tho	Si-N	Vid, 180/120V, 0,4A, 0,6W, 120MHz, (=2N5073)		2a	TO-5		2SD413, 2SD624, 2SD576, 2N5073
BFW 37	Tho	Si-N	Vid, 130/130V, 0,2A, 0,6W, 100MHz		2a	TO-5		BFR 57…59, 2N5058…5059, BFS 89
BFW 38	Tho	Si-N	Vid, 180/120V, 0,4A, 0,6W, >40MHz		2a	TO-5		2SD413, 2SD624, 2SD576
BFW 39(A)	Sgs,Tix	Si-N	Dual, 50/45V, 0,03A, >60MHz, F<4dB, hFE>150		TO-99	(CBE-EBC-)		2N2915(A)
BFW 40(A)	Sgs,Tix	Si-N	=BFW 39: F<3dB, hFE>300		TO-99	(CBE-EBC-)		2N2916(A)
BFW 41	Tho	Si-N	VHF/UHF, 30/15V, 30mA, 0,2W, >600MHz, F<4dB(60MHz)		5g	TO-72		BFS 62, BFW 97, BFX 60, BFX 73, BFX 89++
BFW 42	Tho	Si-N	VHF/UHF Drv, 40/20V, 100mA, 0,6W, >600MHz		2a	TO-39		BFR 36, BFW 16…17, BLW 11
BFW 43	Sgs	Si-P	Vid, 150/150V, 0,1A, 0,4W, 50MHz		2a	TO-18		BF 398, BF 435…437, 2SA1370…1372, ++
BFW 44	Sgs	Si-P	=BFW 43: 0,7W		2a	TO-39		BFQ 35…37, BFT 44…45, 2SB606, ++
BFW 45	Phi	Si-N	Vid, 165/130V, 0,05A, 0,8W, 120MHz		2a	TO-39		BF 257…259, BF 657…659, 2N5058…5059
BFW 46	Mot,Phi,Tix	Si-N	VHF Drv,Out, 36/18V, 0,5/1,5A, PQ>4W(175MHz)		2a	TO-39		BFS 22, MRF 237, 2N3924
BFW 47	Mot,Phi,Tix	Si-N	VHF Drv,Out, 65/40V, 0,35/1A, PQ>2,5W(175MHz)		2a	TO-39		BFS 23, BLY 34, 2N3553
BFW 51(A)	Mot,Sgs	Si-N	Dual, In, 50/45V, >60MHz, hFE>150, F<4dB		TO-71	(EBC-EBC-)		2N2974, 2N2976, 2N2978
BFW 52(A)	Mot,Sgs	Si-N	=BFW 51: hFE>300		TO-71	(EBC-EBC-)		2N2975, 2N2977, 2N2979
BFW 54	Tix	N-FET	50V, Idss=2…10mA, Up<6V, F<100dB(10MHz)		2b	TO-18		-
BFW 55	Tix	N-FET	=BFW 54: F<40dB(10MHz)		2b	TO-18		-
BFW 56	Tix	N-FET	=BFW 54: F<20dB(10MHz)		2b	TO-18		-
BFW 57	Phi	Si-N	LF,S,80/60V, 0,5/1A, 0,3W, >80MHz, <100/-ns,hFE>80		11a	SOT-25	BC 639	7c BC 639, BSX 33, 2N2221A…22A, 2SC4488,++
BFW 58	Phi	Si-N	=BSW 57: hFE=50…150		11a	SOT-25	BC 639	7c BC 939, BSX 33, 2N2221A…22A, 2SC4488,++
BFW 59	Phi	Si-N	=BFW 57: 40/35V		11a	SOT-25	BC 639	7c BC 635, BSV 59, BSX 48…49, 2N2221…22++
BFW 60	Phi	Si-N	=BFW 57: 40/35V, hFE=50…150		11a	SOT-25	BC 639	7c BC 635, BSV 59, BSX 48…49, 2N2221…22++
BFW 61	Phi	N-FET	LF,HF, 25V, 20mA, Idss=2…20mA, Up<8V		5k	TO-72		BF 244…245, BFS 72, 2N3819, 2N3823, ++
BFW 63	Sgs	Si-N	VHF, agc, 40/30V, 600MHz, F<5/Gp=35dB(60MHz)		5k	TO-72		BF 225, BF 314, BF 496, 2SC1393, 2SC1856
BFW 64	Sgs	Si-N	=BFW 63: 650MHz, F<6/Gp=21dB(200MHz)		5k	TO-72		BF 225, BF 314, BF 496, 2SC1393, 2SC1856
BFW 66	Sgs	Si-N	HF/S, 60/60V, 1A, 0,8W, 400MHz, 100/-ns		2a	TO-39		BC 140…141, BSW 27…29, BSX 59…61, ++
BFW 67	Sgs	Si-N	Vid, 300/300V, 0,4A, 0,8W, 60MHz		2a	TO-39		BFQ 38…40, (BF 259, BFR 59, BFS 89,++)[7]
BFW 68	Sgs	Si-N	HF/S, 50/40V, 0,1A 0,36W, 400MHz, 30/240ns		2a	TO-18		BC 547, BSV 59, BSX 48…49, 2N3903…04++
BFW 69	Sgs	Si-N	VHF Drv,Out, 65/40V, 1A, >400MHz		2a	TO-39		BFS 23, BLY 34
BFW 70	Sgs	Si-N	VHF/UHF,IF, 30/30V, 900MHz, F=4,5/Gp=22dB(200MHz)		5k	TO-72		BF 180…183, BF 689, BF 763, 2N2857, ++
BFW 71	Sgs	Si-N	HF,S, 60/60V, 1A, 0,5W, 400MHz, 100/-ns		2a	TO-18		BSS 26, BSS 40…41, 2N4013…4014
BFW 72	Sgs	Si-P						
BFW 73(A)	Sgs	Si-N	UHF Os,Drv, 30/15V, 250mA, >950MHz, hFE=20…120		2a	TO-46/52		(BFR 36, BFW 16…17, BLW 11)[6]
BFW 74	Sgs	Si-N	=BFW 73: hFE=40…120		2a	TO-46		(BFR 36, BFW 16…17, BLW 11)[6]
BFW 75	Sgs	Si-N	UHF, 30/15V, 250mA, >950MHz		Koax	SOD-31		-
BFW 76(A)	Sgs	Si-N	UHF Drv, 30/14V, 80mA, 1,3GHz BFW 76A: 1,5GHz		2a	TO-46		BFR 37, BFW 30, BFX 59, BFX 73
BFW 77(A)	Sgs	Si-N	=BFW 76:		5g	TO-72		BFR 37, BFW 30, BFX 59, BFX 73

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BFW 78	Sgs	Si-N	Min, UHF, 30/14V, 80mA, 1,5GHz						-
BFW 79	Sgs	Si-N	UHF, 30/14V, 80mA, 1,5GHz		Koax	SOD-31			-
BFW 80	Tho	Si-N	LF,HF, 50/30V, 0,2A, 0,6W, >70MHz		2a	TO-5			BC 140…141, BC 301…302, 2N1613, ++
BFW 87	Phi	Si-P	LF,S, 60/60V, 0,5A, 0,3W, >100MHz, hFE=80…320		11a	SOT-25			BC 327, BC 638, BSW 24, 2N2906…07, ++
BFW 88	Phi	Si-P	=BFW 87: hFE=40…120		11a	SOT-25			BC 327, BC 638, BSW 24, 2N2906…07, ++
BFW 89	Phi	Si-P	=BFW 87: 40/40V		11a	SOT-25			BC 328, BC 636, BSW 24, 2N2906…07, ++
BFW 90	Phi	Si-P	=BFW 87: 40/40V, hFE=40…120		11a	SOT-25			BC 328, BC 636, BSW 24, 2N2906…07, ++
BFW 91	Phi	Si-P	=BFW 87: 20/20V, hFE>40		11a	SOT-25			BC 328, BC 636, BSW 24, 2N2906…07, ++
BFW 92	EUR	Si-N	UHF A, 25/15V, 25mA, 0,13W, 1,6GHz, F=4dB(500MHz)		24f	SOT-37	2SC2466	25p	BFR 34, BFT 24, BFW 93
BFW 93	Phi,Sie,Tho	Si-N	UHF A, 18/10V, 50mA, 0,19W, 1,8GHz, F<5dB(500MHz)		24f	SOT-37			BFQ 59…60, BFQ 70, BFR 34, BFT 97
BFW 94	Sgs	Si-N	UHF A, 25/20V, 200mA, 3GHz, Gp=14dB(800MHz)		51r	=TO-131			BFG 34
BFW 96	Phi	MOS-N-FET-d	LF,HF, S, 30V, ±50mA, Idss=1<30mA, Up=1…6,5V		5k	TO-72			BFX 63, BSV 22, BSV 81, BSX 83
BFW 97(K,L,M)	Fer	Si-N	VHF/UHF, 30/15V, 50mA, >600MHz, F=6dB(60MHz)		40e	=TO-98			BF 357, BFR 37, BFW 30, BFX 73
BFW 98	Phi	Si-N	UHF Drv,Out, 36/18V, 400mA, 1GHz		55r	SOT-36			BLW 42, BLW 79, BLX 67, 2N5944…5945
BFW 98 G		Si-N	=BFW 98:		51r	TO-131			BLW 12, BLX 36
BFW 99(S)	Sie	Si-N	UHF A, -/12V, 20mA, 0,2W, 3GHz, F<3dB(1MHz)		5k	TO-72			BFR 15, BFS 55, BFT 66…67
BFWP 21	Ucp	MOS-N-FET	30V, 15mA, Up=5V		5k	TO-72			-
BFX									
BFX		Z-Di	=SM 15T100CA(SMD-Marking)		71a(8x5mm)	SOD-15			›SM 15T….
BFX 10	Sgs	Si-N	Dual, 60/30V, >250MHz		TO-77	(CBE-EBC-)			2N3409…3411
BFX 11	Mot,Sgs,Tix	Si-P	Dual, In, 45/45V, 0,5A, >130MHz, F<5dB(1kHz)		TO-77	(CBE-EBC-)			2N3726…3727, 2N4015…4016
BFX 12	Phi,Tix	Si-P	Uni, 20/15V, 0,1/0,14A, 0,3W, 210MHz, hFE=20…60		2a	TO-18			BC 213, BC 258, BC 308, BC 558, 2SB725++
BFX 13	Phi,Tix	Si-P	=BFX 12: hFE=50…250		2a	TO-18			BC 213, BC 258, BC 308, BC 558, 2SB725++
BFX 14	Sgs	Si-N	VHF/UHF Os, 25/15V, 300mA, 0,8W, 530MHz		2a	TO-5			BFS 22…23, BFS 50, BFX 55
BFX 15	Mot,Sgs,Tix	Si-N	Dual, 80/40V, 0,2A, >50MHz, ΔUbe<5mV		TO-77	(CBE-EBC-)			2N2060, 2N2223, 2N2480
BFX 16	Sgs,Tix	Si-N	3xNPN, 45/45V, 50mA, >60MHz, F<3db(1kHz), ΔUbe<5mV		TO-100	(ECBECBECB			-
BFX 17	Sgs,Tix	Si-N	VHF Drv,Out, 60/40V, 1A, PQ=1,8W(150MHz/18V)		2a	TO-39			BFS 23, BFW 47, BLY 34, 2N3553
BFX 18	Sgs	Si-N	HF,IF, 30/30V, 550MHz, F<5/Gp=32dB(60MHz)		5g	TO-72			BF 167, BF 198, BFX 31, BFX 60, BFX 73++
BFX 19	Sgs	Si-N	=BFX 18: F<6/Gp=20dB(200MHz)		5g	TO-72			BF 167, BF 198, BFX 31, BFX 60, BFX 73++
BFX 20	Sgs	Si-N	=BFX 18: F<7,5/Gp=16dB(450MHz)		5g	TO-72			BF 167, BF 198, BFX 31, BFX 60, BFX 73++
BFX 21	Sgs	Si-N	=BFX 18: F<9/Gp=10dB(800MHz)		5g	TO-72			BF 167, BF 198, BFX 31, BFX 60, BFX 73++
BFX 29	Nsc,Phi,Tix	Si-P	HF,S, 60V, 0,6A, 0,6W, >100MHz, <60/150ns		2a	TO-39			BC 161, BC 303, BSW 40, 2N2904…2905, ++
BFX 30	Phi,Tix	Si-P	S, 65/65V, 0,6A, 0,6W, <50/290ns		2a	TO-39			BC 161, BC 303, BSW 40, 2N2904…2905, ++
BFX 31	Sgs	Si-N	VHF, In, agc, 30/30V, 500MHz, F<3/Gp=32dB(60MHz)		5g	TO-72			BF 225, BF 314, BFX 60, BFX 73, 2SC1856+
BFX 32	Aeg	Si-N	VHF/UHF, 35/25V, 30mA, 850MHz		9f				BF 377…78, BF689, 2N2857, 2SC3776…77++
BFX 33	Aeg	Si-N	VHF A,Drv, 55/30V, 0,4A, 600MHz, PQ>0,15W(200MHz)		2a	TO-39			BFS 23, BFW 47, BFX 55, 2N3866
BFX 34	Aeg,Phi,++	Si-N	LF,S Drv, 120/60V, 2/5A, 0,87W, 100MHz,<600/1200ns	{BSS44	2a	TO-39			BFT 34, 2N4895…4896
BFX 35	Mot,Sgs,Tix	Si-P	LF,S, 40/40V, 0,6A, 0,4W, >200MHz		2a	TO-18			BC 327, BC 636, BSW 24, 2N2906…07, ++
BFX 36	Mot,Sgs,Tix	Si-P	Dual In, 60/60V, 0,1A, 110MHz, F<3dB(1k), ΔUbe<3mV		TO-77	(CBE-EBC-)			2N3806…3811, 2N4016…4016
BFX 37	Phi,Sgs,++	Si-P	LF In, 90/80V, 0,1A, 0,36W, 70MHz, F<2,5dB(1kHz)		2a	TO-18			=2N3963, 2SA970, 2SA1049, 2SA1136, ++
BFX 38	Sgs,Tix,++	Si-P	LF,S, 55/55V, 1A, 0,8W, 150MHz, 33/160ns, hFE>85		2a	TO-39			BC 161, BSV 82, BSW 40, 2N4030…4033
BFX 39	Sgs,Tix,++	Si-P	=BFX 38: hFE=70>40		2a	TO-39			BC 161, BSV 82, BSW 40, 2N4030…4033
BFX 40	Sgs,Tix,++	Si-P	=BFX 38: 75/75V		2a	TO-39			BC 461, BSV 82, BSW 40, 2N4031, 2N4033
BFX 41	Sgs,Tix,++	Si-P	=BFX 38: 75/75V, hFE=70>40		2a	TO-39			BC 461, BSV 82, BSW 40, 2N4031, 2N4033
BFX 42	Sgs	Si-N	UHF, RadH, 15/10V, 1,4GHz		2a	TO-46			-
BFX 43	Phi,Tix	Si-N	VHF/S, 30/15V, 0,2A, >500MHz, hFE=20…60,(=2N2368)		2a	TO-18			BSS 10…12, BSX 19…20, 2N2368, ++
BFX 44	Phi,Tix	Si-N	=BFX 43: 40/15V, hFE=40…120, (=2N2369)		2a	TO-18			BSS 10…11, BSX 19…20, 2N2369, ++
BFX 45	Phi	Si-N	LF,S, 30/20V, 0,1/0,2A, 0,125W, >175MHz,<200/400ns		12a	SOT-33			BC 548, BSW 41, BSX 87…88, BSY 63, ++
BFX 47	Phi	Si-N	UHF A, 30/24V, 20mA, >1GHz, Gp=15dB(750MHz)		5g	TO-72			BFR 37, BFW 30, BFX 73, 2SC3776…77
BFX 48	Mot,Sgs,Tix	Si-P	HF,S, 30V, 0,1A, 550MHz, 20/95ns, F<6dB(100MHz)		2a	TO-18			BF 440, BSW 24, 2N3905…06, 2N4034…35++
BFX 49	Phi	Si-N	UHF A,Drv, 65/36V, 250mA, 1,3GHz		55r	SOT-56			BFR 64…65, BFT 91, BLX 91
BFX 49 G		Si-N	=BFX 49:		51r	TO-131			-
BFX 50	Phi,Tix	Si-N	LF,S, 80/35V, 1A, 0,6W, >60MHz		2a	TO-18			BC 639, BSS 59, 2N4014, 2SC4488, 2SD774+
BFX 51	Phi,Tix	Si-N	LF,S, 60/30V, 1A, 0,6W, >50MHz		2a	TO-18			BC 637, BSS 26, BSS 40…41, 2N4014
BFX 52	Phi,Tix	Si-N	LF,S, 40/20V, 1A, 0,6W, >60MHz		2a	TO-18			BC 635, BSS 23, 2N4013…14, 2SC4485,++
BFX 53	Aeg	Si-N	UHF, 20/12V, 25mA, >1,3GHz		24c	=SOT-37			BF 362…363, BFR 34, BFT 24
BFX 55	Sie	Si-N	VHF A,Drv, 60/40V, 400mA, 700MHz, Gp=16dB(200MHz)		2a	TO-39			BFS 23, BFW 47, BFX 33, 2N3553, 2N3866
BFX 56(I….III)	Sie	Si-N	VHF A,Drv, 60/40V, 300mA, >350MHz		2a	TO-39			BFS 23, BFW 47, BFX 55, 2N3553, 2N3866
BFX 57(I….III)	Sie	Si-N	VHF A, 30/20V, 100mA, >600MHz		5g	TO-12			BFR 36, BFW 16…17
BFX 58(I….III)	Sie	Si-N	VHF A,Drv, 60/40V, 400mA, >600MHz		5g	TO-12			BFS 23, BFW 47, BFX 55, 2N3553, 2N3866
BFX 58 D		Si-N	=BFX 58(I…III):		2a	TO-39			BFS 23, BFW 47, BFX 55, 2N3553, 2N3866
BFX 59(F,R)	Sie	Si-N	VHF/UHF A,Drv, 30V, 100mA, 1GHz, F<4,5dB(200MHz) BFX 59F: 1,05GHz, BFX 59R: 1,1GHz		5g	TO-72	2SC2570A[7]	7f	2SC3337, 2SC3779, (BFR37, BFW30, BFX73)[7]
BFX 60	Sie	Si-N	VHF, 40/25V, 25mA, 550MHz, F=5dB(200MHz)		5k	TO-72	BF 199	7d	BF225, BF314, BF496, 2SC1393, 2SC1856,++
BFX 61	Tho	Si-N	LF,S Drv, 80/80V, 1A, 180MHz		2a	TO-39			BC 141, BSS 42, BSX 46…47, 2N3107…08++
BFX 62	Sie,Tho	Si-N	UHF Inp,Mx,Os, 30V, 12mA, 675MHz,F=5/Gp=12dB(800M)		5g	TO-72	2SC2570A	7f	BF 180…183, BF 689, BF 763, 2N2857, ++
BFX 63	Phi	MOS-N-FET-d	=BFW 96:		5m	TO-33			›BFW 96
BFX 65	Aeg,Phi,++	Si-P	LF In, 45/45V, 0,05A, 0,36W, >40MHz, F<3dB(1kHz)		2a	TO-18			BC 214, BC 415…416, BC 560, 2SA1137,++
BFX 66	Mot,Sgs	Si-N-Darl	100/60V, 0,2A, 0,5W, hFE=1600…8000, F<6dB(1kHz)		5	TO-72			=2N998
BFX 67	Mot,Sgs	Si-N-Darl	60/60V, 0,5A, 0,5W, hFE=7k…70k		5	TO-72			=2N999
BFX 68	Mot,Sgs,Tix	Si-N	LF,S, 75/30V, 1A, 0,7W, >70MHz, F<8dB(1kHz)		2a	TO-39			BC 141, BSX 45…47, BSY 53…54, 2N1711++
BFX 68 A		Si-N	=BFX 68: 80/40V, 0,8W, F<7dB(1kHz)		2a	TO-39			BC 141, BSX 45…47, 2N3109…3110, ++
BFX 69	Mot,Sgs,Tix	Si-N	LF,S, 75/30V, 1A, 0,8W, >60MHz, F<12dB(1kHz)		2a	TO-39			BC 141, BSX 45…47, BSY 53…54, 2N1613++
BFX 69 A		Si-N	=BFX 69: 80/40V		2a	TO-39			BC 141, BSX 45…47, 2N3109…3110, ++
BFX 70	Mot,Sgs,Tix	Si-N	Dual, 100/60V, 0,5A, 100MHz, F<8db(1k), ΔUbe<5mV		TO-77	(CBE-EBC-)			2N2060, 2N2223
BFX 71	Mot,Sgs,Tix	Si-N	Dual, 100/50V, 0,5A, 100MHz, ΔUbe<15mV		TO-77	(CBE-EBC-)			2N2060, 2N2223
BFX 72	Mot,Sgs,Tix	Si-N	Dual, 100/60V, 0,5A, 100MHz, ΔUbe<5mV		TO-77	(CBE-EBC-)			2N2060, 2N2223
BFX 73	Mot,Sgs,Tix	Si-N	VHF/UHF, 30/15V, 50mA, 900MHz, Gp=18db(200MHz)		5g	TO-72			BF 357, BFR 37, BFW 30, BFX 59, 2SC3776+
BFX 74	Mot,Sgs,Tix	Si-P	LF Drv, 50/35V, 0,5A, 0,6W, 90MHz		2a	TO-39	BC 161	2a	BC 161, BC 303…304, 2N2904…2905, ++
BFX 74 A		Si-P	=BFX 74: 60/60V, 0,8W, 150MHz		2a	TO-39	BC 161	2a	BC 161, BC 303…304, 2N2904…2905, ++
BFX 75	Phi	Si-N	Min, HF, 30/20V, 30mA, >200MHz, hFE=70…280		Chip				-
BFX 76	Phi	Si-N	=BFX 75: hFE=33…110		Chip				-
BFX 77	Tho	Si-N	HF, 50/30V, 300MHz		5k	TO-72			BF 167, BF 198, BF 225, BF 310, 2SC2215+
BFX 78	Sgs	MOS-N-FET-d	FM/VHF In, 15V, Idss=16mA, F=2,7dB(100MHz)		5k	TO-72			-
BFX 79	Sgs	Si-N/P	1x NPN + 1x PNP, 80/60V, 0,6A, 100MHz, F=3dB(1kHz)		TO-77	(CBE-EBC-)			2N4854…4855
BFX 80	Sgs	Si-N/P	1x NPN + 1x PNP, 60/60V, 0,2A, >40MHz, F<4dB(1kHz)		TO-77	(CBE-EBC-)			2N4854…4855
BFX 81	Sgs	Si-N/P	1x NPN + 1x PNP, 25V, 0,2A, >350MHz, <60/90ns		TO-77	(CBE-EBC-)			2N4854…4855
BFX 82	Sgs	P-FET	LF,HF In, 25V, Idss=17mA, Up=5V, F=1,5dB(1kHz)		2a	TO-18			-
BFX 83	Sgs	P-FET	LF,HF In, 25V, Idss=6,8mA, Up=9V, F=1,5dB(1kHz)		2a	TO-18			-
BFX 84	Phi,Tix,++	Si-N	LF,S, 100/60V, 1A, 0,8W, >50MHz, hFE>30, 55/360ns		2a	TO-39	BC 141	2a	BC 141, BSX 46…47, 2N3107…3108, ++
BFX 85	Phi,Tix,++	Si-N	=BFX 84: hFE=142>70		2a	TO-39	BC 141	2a	BC 141, BSX 46…47, 2N3107…3108, ++

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BFX 86	Phi,Tix,++	Si-N	=BFX 84: 40/35V, hFE=142>70		2a	TO-39	BC 141	2a	BC 140…141, BSX 45…47, 2N3107…3110,++
BFX 87	Phi,Tix,++	Si-P	S, 50/50V, 0,6A, 0,53W, >100MHz, <60/150ns		2a	TO-39			BSW 40, 2N2904…2905, 2N3468, ++
BFX 88	Phi,Tix,++	Si-P	=BFX 87: 40/40V		2a	TO-39			BSW 40, 2N2904…2905, 2N3468, ++
BFX 89	EUR	Si-N	UHF A, 30/15V, 25mA, 1,3GHz, F=7/Gp=7dB(800MHz)		5g	TO-72	2SC2570A	7f	BFR 37, BFW 30, BFW 92…93, BFX 73
BFX 90	Mot,Sgs	Si-P	LF In, 180/180V, 0.05A, 0,4W, 60MHz, F<3dB(1kHz)		2a	TO-18			2N3930, (BF 421, BF 423, BF 436…437)
BFX 91	Mot,Sgs	Si-P	=BFX 90: 0,7W		2a	TO-39			2N3931, (BFQ 36)
BFX 92	Mot,Sgs,Tix	Si-N	LF In, 50/45V, 0,03A, 0,3W, 45MHz, hFE>40, F<4dB		2a	TO-18			BC 382, BC 414, BC 550, =2N929, 2N3117
BFX 92 A		Si-N	=BFX 92: 60/60V, 0,05A, 0,36W, >60MHz, F<3dB		2a	TO-18			=2N2483, 2N3117, 2SC2390
BFX 93	Mot,Sgs,Tix	Si-N	=BFX 92: hFE=100…300		2a	TO-18			BC 382, BC 414, BC 550, =2N930, 2N3117
BFX 93 A		Si-N	=BFX 92A: hFE=100…300		2a	TO-18			=2N2484, 2N3117, 2SC2390
BFX 94(A)	Mot,Sgs,Tix	Si-N	=2N2221(A)		2a	TO-18	›2N2221(A)		›2N2221(A)
BFX 95(A)	Mot,Sgs,Tix	Si-N	=2N2222(A)		2a	TO-18	›2N2222(A)		›2N2222(A)
BFX 96(A)	Mot,Sgs,Tix	Si-N	=2N2218(A)		2a	TO-39	›2N2218(A)		›2N2218(A)
BFX 97(A)	Mot,Sgs,Tix	Si-N	=2N2219(A)		2a	TO-39	›2N2219(A)		›2N2219(A)
BFX 98	Sgs,Tix	Si-N	Vid, 150/150V, 0,1A, 0,8W, 90MHz	{BFW44	2a	TO-39			BF 257…259, BF 657…659, 2N5058…5059
BFX 99	Mot,Sgs,Tix	Si-N	Dual, 100/60V, 0,5A, 100MHz, F<8dB(1k), ΔUbe<1,5mV		TO-77	(CBE-EBC-)			2N2060, 2N2223
BFX 152	Aeg	Si-N	Vid, hi-res, 100/100V, 0,3A, 0,83W, >500MHz		7e	TO-92			-
BFX 154	Aeg	Si-N	Vid, hi-res, 100/100V, 0,3A, 2W(Tc=110°), >500M		14h	TO-126	2SC3599	14h	2SC3599
BFX 155	Aeg	Si-P	Vid, hi-res, 100/100V, 0,3A, 2W(Tc=110°), >500M		14h	TO-126	2SA1405	14h	2SA1405
BFX 156	Aeg	Si-N	=BFX 154: 5W(Tc=25°)		13h	TO-202	(2SC3599)[4]	14h	(2SC3599)[4]
BFX 157	Aeg	Si-P	=BFX 155: 5W(Tc=25°)		13h	TO-202	(2SA1405)[4]	14h	(2SA1405)[4]
BFY…BFZ									
BFY 10	Phi	Si-N	HF,S, 45/45V, 0,05A, 0,3W, 120MHz, hFE=25…50		2a	TO-5			BC 107, BC 167, BC 182, BC 237, BC 546++
BFY 11	Phi	Si-N	=BFY 10: hFE=40…125		2a	TO-5			BC 107, BC 167, BC 182, BC 237, BC 546++
BFY 12(B,C,D)	Sie	Si-N	HF,S, 60/40V, 0,5A, >180MHz, <40/720ns		2a	TO-39			BSW 39, BSW 51…52, 2N2218…2219, ++
BFY 13(B,C,D)	Sie	Si-N	=BFY 12: 80/60V, 0,35A		2a	TO-39			BSW 39, BSW 53…54, 2N2218A…2219A, ++
BFY 14(B,C,D)	Sie	Si-N	=BFY 12: 100/80V, 0,25A		2a	TO-39			BSW 39, 2N1893, 2N3723
BFY 15	Itt,Sgs	Si-N	HF/S, 40/20V, 0,5A, 0,6W, 100MHz, 120/-ns		2a	TO-5			BC 140…141, BC 300…302, 2N2218…19, ++
BFY 16	Itt	Si-N	=BFY 15: 150MHz		2a	TO-5			BC 140…141, BC 300…302, 2N2218…19, ++
BFY 17	Itt	Si-N	HF,S, 40/25V, 0,1/0,2A, 0,6W, 245MHz, F=5dB(100k) 22/900ns		2a	TO-5			BC 140…141, BC 300…302, 2N2218…19, ++
BFY 18	Itt	Si-N	=BFY 17: 0,3W		2a	TO-18			BC 107, BSW 41, BSY 63, 2N2221…22, ++
BFY 19	Itt	Si-N	HF,S, 30/20V, 0,1A, 0,3W, 400MHz, F<13dB(1kHz)		2a	TO-18			BC 108, BSW 41, BSY 63, 2N2221…22, ++
BFY 20	Itt	Si-N	Dual, 40/15V, 0,2A, 245MHz, ΔUbe<10mV		TO-77	(CBE-EBC-)			2N3409…3411
BFY 21	Itt	Si-N	Dual, 40/15V, 0,2A, >200MHz		TO-77	(CBE-EBC-)			2N3409…3411
BFY 22	Itt	Si-N	Min, LF, 5/5V, 0,05A, 20MHz, hfe=30…90, F=7dB(1k)		36c	(1,8mmØ)			BC 121…123, BC 146
BFY 23(a)	Itt	Si-N	=BFY 22: hfe=70…220, BFY23a: hfe=300>200		36c	(1,8mmØ)			BC 121…123, BC 146
BFY 24	Itt	Si-N	=BFY 22: hfe=45…130		36c	(1,8mmØ)			BC 121…123, BC 146
BFY 25	Itt	Si-N	S, 60/40V, 0,2A, 0,6W, >200MHz, 22/-ns		2a	TO-5			BSW 27…28, BSW 51…52, 2N2218…19, ++
BFY 26	Itt	Si-N	=BFY 25: 0,36W		2a	TO-18			BSV 59, BSX 49, 2N2221…2222, ++
BFY 27	Aeg	Si-N	=2N915		2a	TO-18			›2N915
BFY 28	Itt	Si-N	LF,HF, 60/30V, 0,1A, 0,3W, 400MHz, F<13dB(1kHz)		2a	TO-18			BC 182, BC 190, BC 546, 2N2221…22, ++
BFY 29	Itt	Si-N	Min, LF, 45/30V, 0,05A, 20MHz, hfe=30…90, F=7dB		36c	(1,8mmØ)			BC 123
BFY 30	Itt	Si-N	=BFY 29: hfe=70…220		36c	(1,8mmØ)			BC 123
BFY 31	Sie	Si-N	LF,S, 75/30V, 0,5A, >60MHz		2a	TO-39			BC 140…141, BC 300…301, 2N2218A…19A++
BFY 33	Sie,Tsm	Si-N	LF,HF,S, 50/24V, 0,5A, 0,75W, 80MHz, F=5dB(1kHz)		2a	TO-39			BC 140…141, BC 300…301, 2N2218…19, ++
BFY 34	Mot,Sie,++	Si-N	=BFY 33: 75/30V		2a	TO-39			BC 140…141, BC 300…301, 2N2218A…19A++
BFY 37(i)	Itt	Si-N	LF,S, 25/20V, 0,1A, 0,3W, 270MHz, BFY37i: Iso		2a	TO-18	BC 546	7a	BC 108, BC 168, BC 183, BC 238, BC 548++
BFY 39…(i)	Itt	Si-N	LF,S, 45/25V, 0,1A, 0,3W, 150MHz, BFY39i: Iso		2a	TO-18	BC 546	7a	BC 107, BC 167, BC 183, BC 237, BC 547++
BFY 40	Itt,Tix	Si-N	LF,S, 60/30V, 0,8A, 0,8W, 60MHz		2a	TO-39	BC 141	2a	BC 140…141, BC 300…302, 2N2218…19, ++
BFY 41	Itt,Tix	Si-N	LF,S, 120V, 0,6A, 0,8W, 60MHz		2a	TO-39	BC 141	2a	BC 300, BSX 47, BSY 55…56, 2N1893, ++
BFY 42		Si-N	=BC 107						›BC 107
BFY 43	Itt	Si-N	Vid, 140/140V, 0,1A, 0,8W, 60MHz		2a	TO-39	BF 259	2a	BF 257…259, BF 657…659, 2N5058…5059
BFY 44	Phi,Tix	Si-N	VHF A, Drv Out, 80/60V, 1A, PQ=2,1W(180MHz/40V)		2a	TO-39			BFS 23, BFW 47, BLY 34, 2N3553
BFY 45	Sie,Tix	Si-N	Nixie Drv, 140/90V, 0,03A, 0,7W, 130MHz		2a	TO-39			BF 257…259, BF 657…659, 2N5058…5059
BFY 46	Mot,Sie,++	Si-N	=2N1711		2a	TO-39			›2N1711
BFY 47	Sie	Si-N	Min, LF, 5/5V, 0,05A, 0,075W, 50MHz, F<5dB(1kHz)		36c	(1,8mmØ)			BC 121…123, BC 146
BFY 48	Sie	Si-N	=BFY 47: 30/20V		36c	(1,8mmØ)			BC 122…123
BFY 49	Sie	Si-N	=BFY 47: 45/30V		36c	(1,8mmØ)			BC 123
BFY 50(E)	EUR	Si-N	HF/S, 80/35V, 1A, 0,8W, 100MHz, 55/175ns, hFE>30 BFY 50E [Tho]: 80/40V, hFE>44		2a	TO-39	BC 141	2a	BC 140…141, BSW 39, 2N3444
BFY 51	EUR	Si-N	=BFY 50: 60/30V, hFE=70>40		2a	TO-39	BC 141	2a	BC 140…141, BSW 27…28, 2N3252…53, ++
BFY 52	EUR	Si-N	=BFY 50: 40/20V, hFE=130>60		2a	TO-39	BC 141	2a	BC 140…141, BSW 27…29, 2N3252…53, ++
BFY 53	Phi	Si-N	=BFY 50: 40/20V		2a	TO-39	BC 141	2a	BC 140…141, BSW 27…29, 2N3252…53, ++
BFY 55	Mot,Phi,Tix	Si-N	HF,S, 80/35V, 1A, 0,7W, >60MHz, (=2N2297)		2a	TO-39			BC 140…141, BSX 45…47, 2N3707…10, ++
BFY 56(A,B)	Aeg,Tix,++	Si-N	HF,S, 60…80V, 1A, 0,8W, 150/350ns BFY56: 80/45V, A: 80/55V, B: 60/60V		2a	TO-39			BC 140…141, BSW 39, 2N3444
BFY 57	Sgs,Tix,++	Si-N	LF,Vid, 125/125V, 0,1A, 0,8W, >40MHz		2a	TO-39			BF 257…259, BF 657…659, 2N5058…5059
BFY 63	Sgs,Tix	Si-N	VHF A,Drv, 30/15V, 100mA, 750MHz, Gp=6dB(250MHz)		2a	TO-39			BFR 36, BFW 16…17
BFY 64	Sgs,Tix,++	Si-P	LF,S, 40/40V, 0,6A, 0,7W, 250MHz, 35/70ns		2a	TO-39			BSV 82, BSW 23, BSW 40, 2N3467…68, ++
BFY 65	Aeg,Tix	Si-N	Nixie Drv, 100/80V, 0,1A, 0,6W, >50MHz		2a	TO-39			BF 257…259, BF 657…659, 2N5058…5059
BFY 66	Aeg,Mot	Si-N	=2N918		5g	TO-72			›2N918
BFY 67(A,C)	Mot,Phi,Tix	Si-N	=2N1613		2a	TO-5			›2N1613
BFY 68(A)	Mot,Phi,Tix	Si-N	=2N1711		2a	TO-5			›2N1711
BFY 69(A,B)	Aeg	Si-N	Min, LF, 25/15V, 0,1A, 0,1W, >50MHz BFY69A: In, F<dB(1kHz), B: Fig. 36c(TOM-23)		36c	(TOM-13)			BC 122…123
BFY 70	Phi,Tix	Si-N	VHF Drv,Out, 60/40V, 1A, PQ=1,5W(180MHz)		2a	TO-39			BFS 23, BFW 47, BLY 34, 2N3553
BFY 72	Nsc,Sgs,Tix	Si-N	HF/S, 50/28V, 0,5A, 0,8W, 350ns, 14/80ns		2a	TO-39			BSS 13, BSS 27…29, 2N3722…3725, ++
BFY 73	Sgs,Tix	Si-N	HF/S, 60/30V, 0,8A, 0,8W, >250MHz, <60/-ns		2a	TO-39			BSS 13, BSS 27…29, 2N3722…3725, ++
BFY 74	Mot,Sgs,Tix	Si-N	HF/S, 60/45V, 0,1A, 0,36W, 360MHz, hFE=40…180		2a	TO-18			BC 190, BC 546, 2N2221…22, 2SD767,++
BFY 75	Mot,Sgs,Tix	Si-N	=BFY 74: hFE=65…300		2a	TO-18			BC 190, BC 546, 2N2221…22, 2SD767,++
BFY 76	Sgs,Tix,++	Si-N	LF In, 45/45V, 0,05A, 0,36W, 100MHz, hFE>30, F<4dB		2a	TO-18			BC 184, BC 413…414, BC 550, 2SC2675,++
BFY 77	Sgs,Tix	Si-N	=BFY 76: hFE=80…600, F=1,8dB(1kHz)		2a	TO-18			BC 184, BC 413…414, BC 550, 2SC2675,++
BFY 78	Mot,Sgs,Tix	Si-N	VHF, 25/12V, 50mA, 0,3W, 900MHz, Gp=18dB(200MHz)		2a	TO-18			BFR 37, BFW 30, BFX 59, BFX 73
BFY 79	Sgs	Si-N	HF,IF, agc, 30/30V, >400MHz, F<5,5/Gp=30dB(45MHz)		5g	TO-72			BF 167, BF 198, BF 225, BF 310, 2SC2215+
BFY 80	Aeg,Tix	Si-N	Nixie Drv, 100/80V, 0,1/0,2A, 0,26W, >50MHz		2a	TO-18			BF 297…299, BFR 86…89, BSS 38, BSX 21
BFY 81	Mot,Sgs,Tix	Si-N	Dual, 45/45V, 0,05A, >60MHz, F<4dB(1k), ΔUbe<10mV		TO-77	(CBE-EBC-)			2N2639…2644, 2N2913…2920
BFY 82	Sgs,Tix	Si-N	Dual, 60/45V, 0,1A, >250MHz, ΔUbe<15mV		TO-77	(CBE-EBC-)			-
BFY 83	Sgs,Tix	Si-N	Dual, 100/60V, 0,2A, >50MHz, Ube<15mV		TO-77	(CBE-EBC-)			2N2060, 2N2223, 2N2652
BFY 84	Mot,Sgs,Tix	Si-N	Dual,30/12V, 0,2A, >600MHz, F<6dB(60MHz),ΔUbe<15mV		TO-77	(CBE-EBC-)			2N3423…3424
BFY 85(A,B)	Aeg,Tix	Si-N	Dual, 45/45V, 0,1A, >50MHz, F<6dB(1k), ΔUbe<10mV BFY85: hFE=100…360, A: 100…200, B: 180…360		TO-77	(CBE-EBC-)			2N2639…2644, 2N2913…2920, 2N2453

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
BFY 86(A,B)	Aeg,Tix	Si-N	=BFY 85: ΔUbe<5mV		TO-77	(CBE-EBC-)		2N2639...2644, 2N2913...2920, 2N2453
BFY 87(A)	Aeg	Si-N	Min, LF, 25/15V, 0,1A, 0,05W, >50MHz BFY 87A: In, F<6dB(1kHz)		36c	(TOM-23)		BC 122...123
BFY 88	Aeg	Si-N	UHF Inp,Mx,Os, 40V, 850MHz, F<6,5/Gp=15dB(500MHz)		5k	TO-72		BF 180...183, BF 689, BF 763, 2N2857, ++
BFY 90(B)	EUR	Si-N	VHF/UHF A,Drv, 30V, 25mA, 1,1GHz, Gp=23dB(800MHz)		5g	TO-72		BFR 37, BFW 30, BFX 59, BFX 73
BFY 91	Mot,Tho,Tix	Si-N	Dual, 45/45V, 0,03A, 60MHz, F=4dB(1k), ΔUbe<5mV		TO-77	(CBE-EBC-)		2N2639...2644, 2N2913...2920
BFY 92	Mot,Tho,Tix	Si-N	=BFY 91: ΔUbe<10mV		TO-77	(CBE-EBC-)		2N2639...2644, 2N2913...2920
BFY 94	Mot,Tix	Si-P	LF,S, 50/40V, 0,6A, 0,8W, >100MHz, <100/-ns		2a	TO-39		BC 161, BC 303...304, 2N2904...2905, ++
BFY 95	Tix	Si-P	LF,S, 30/30V, 0,6A, 0,36W, >100MHz		2a	TO-18		BC 327...28, BC 636, 2N2906...07, 2SA1705+
BFY 99	Sie	Si-N	VHF A,Drv, 65/40V, 1A, 500MHz, PQ>2.5W(260MHz)		2a	TO-39		BFS 23, BFW 47, BLY 34, 2N3553
BFZ 10	Phi	Si-P	LF,S, 15V, 10mA, 0,05W, 3,5MHz		1a			BC 213, BC 258, BC 308, BC 558, 2SB725++
BG....BL								
BG		Si-Di	=1SS269 (SMD-Marking)		35	SOT-23		›1SS269
BG		Si-Di	=1SS313 (SMD-Marking)		35(2mm)	SOT-323		›1SS313
BG		Si-P	=2SB1124 (SMD-Marking)		39	SOT-89		›2SB1124
BG		Si-N	=2SC3440-G (SMD-Marking)		35	SOT-23		›2SC3440
BG		Si-N	=2SC3443-G (SMD-Marking)		39	SOT-89		›2SC3443
BG		Si-N	=BCP 55-10 (SMD-Marking)		≈39°	SOT-223		›BCP 55-10
BG		Si-N	=BCX 55-10 (SMD-Marking)		39	SOT-89		›BCX 55-10
BG(p,s)		Si-P	=BCX 71G (SMD-Marking)		35	SOT-23		›BCX 71G
BG 2011 SM	Rhm	GaAs-FET-IC	Breitb.-Vst./Wideband Amp, 6V, F=2,1/Gp=10dB(1GHz)		44	SOT-143		-
BG 3011 F,CF	Rhm	GaAs-FET-IC	Frequenzteiler/Prescaler, 1:128/129, 1,1GHz, 5V		8-MDIP	CF=Ceram.		-
BG 3012 F,CF	Rhm	GaAs-FET-IC	Frequenzteiler/Prescaler, 1:128/129, 850MHz, 5V		8-MDIP	CF=Ceram.		-
BG 3013 F,CF	Rhm	GaAs-FET-IC	Frequenzteiler/Prescaler, 1:128/129, 1,1GHz, 5V		8-MDIP	CF=Ceram.		-
BGD		Si-N/P	Module, Spezialtypen/Special Devices					
BGH		Z-Di	=SM 15T 150C(SMD-Marking)		71a(8x5mm)	SOD-15		›SM 15T....
BGK		Z-Di	=SM 15T150CA(SMD-Marking)		71a(8x5mm)	SOD-15		›SM 15T....
BGU		Z-Di	=SM 15T 200C(SMD-Marking)		71a(8x5mm)	SOD-15		›SM 15T....
BGV		Z-Di	=SM 15T200CA(SMD-Marking)		71a(8x5mm)	SOD-15		›SM 15T....
BGX 11/... ...17/...	Phi	Thy	Thy Module/Modules			TO-240		-
BGX 50(A)	Sie	Si-Br	SMD, HF Br-Rr, 50V, 0,1A, ...50MHz		44	SOT-143		-
BGX 88(/01)	Phi	Si	VHF/UHF-Modul, F=6dB/Gp=34,5dB(40...450MHz)					-
BGX 885	Phi	Si	VHF/UHF-Modul, F<8dB/Gp=17dB(40...860MHz)					-
BGY		Si-N/P, Di	Module, Spezialtypen/Special Devices					
BH		Si-Di	=1SS295 (SMD-Marking)		35	SOT-23		›1SS295
BH		Si-Di	=1SS350 (SMD-Marking)		35	SOT-23		›1SS350
BH		Si-P	=2SB1001-BH (SMD-Marking)		39	SOT-89		›2SB1001
BH		Si-P	=2SB1125 (SMD-Marking)		39	SOT-89		›2SB1125
BH		Si-N	=BCX 56 (SMD-Marking)		39	SOT-89		›BCX 56
BH(p,s)		Si-P	=BCX 71H (SMD-Marking)		35	SOT-23		›BCX 71H
BH 7502 K1	Rhm	LIN-IC	VC, VHS-NTSC Video Signal Processor		80-MP			-
BH 7507 K1	Rhm	LIN-IC	VC, VHS-PAL Video Signal Processor		80-MP			-
BH 7513 AKV	Rhm	LIN-IC	VC, VHS-NTSC Video Signal Processor		80-MP			-
BH 7517 K1	Rhm	LIN-IC	VC, VHS-PAL Video Signal Processor		80-MP			-
BH 7518 AKV	Rhm	LIN-IC	VC, VHS-PAL Video Signal Processor		80-MP			-
BH 7733 S	Rhm	LIN-IC	Audio, Multiple Input Selection Switch, Ucc=±5V		24-SDIP			-
BH 7773 KS	Rhm	BiCMOS-IC	VC, Audio Signal Processor (Normal & HiFi)		100-MP			-
BH 9590 FP-Y	Rhm	BiCMOS-IC	µComp, SCSI Bus, Active Terminator		25-SMDIP+b			-
BH 9610 K	Rhm	BiCMOS-IC	Optical Disk, Laser Power Controller		44-MP			-
BHM		Si-N	=2SC4699K-M (SMD-Marking)		35	SOT-23		›2SC4699K
BHM		Si-N	=2SC4700-M (SMD-Marking)		35(2mm)	SOT-323		›2SC4700
BHN		Si-N	=2SC4699K-N (SMD-Marking)		35	SOT-23		›2SC4699K
BHN		Si-N	=2SC4700-N (SMD-Marking)		35(2mm)	SOT-323		›2SC4700
BHP		Si-P	=2SB1386-P (SMD-Marking)		39	SOT-89		›2SB1386
BHP		Si-N	=2SC4699K-P (SMD-Marking)		35	SOT-23		›2SC4699K
BHP		Si-N	=2SC4700-P (SMD-Marking)		35(2mm)	SOT-323		›2SC4700
BHQ		Si-P	=2SB1386-Q (SMD-Marking)		39	SOT-89		›2SB1386
BHR		Si-P	=2SB1386-R (SMD-Marking)		39	SOT-89		›2SB1386
BI		Si-P	=2SB1126 (SMD-Marking)		39	SOT-89		›2SB1126
BIQ		N-FET	=2SK541-BIQ (SMD-Marking)		35	SOT-23		›2SK541
BIR		N-FET	=2SK541-BIR (SMD-Marking)		35	SOT-23		›2SK541
BIS		N-FET	=2SK541-BIS (SMD-Marking)		35	SOT-23		›2SK541
BJ		Si-P	=2SB1001-BJ (SMD-Marking)		39	SOT-89		›2SB1001
BJ		Si-P	=2SB1302 (SMD-Marking)		39	SOT-89		›2SB1302
BJ		Si-N	=BCP 56 (SMD-Marking)		≈39°	SOT-223		›BCP 56
BJ		Si-N	=BCX 56-6 (SMD-Marking)		39	SOT-89		›BCX 56
BJ(p,s)		Si-P	=BCX 71J (SMD-Marking)		35	SOT-23		›BCX 71J
BJE		Si-P	=2SB1427-E (SMD-Marking)		39	SOT-89		›2SB1427
BJS		Si-P	=2SB1427-S (SMD-Marking)		39	SOT-89		›2SB1427
BJU		Si-P	=2SB1427-U (SMD-Marking)		39	SOT-89		›2SB1427
BJU		Si-N	=2SD2226K-U (SMD-Marking)		35	SOT-23		›2SD2226K
BJU		Si-N	=2SD2351-U (SMD-Marking)		35(2mm)	SOT-323		›2SD2351
BJV		Si-N	=2SD2226K-V (SMD-Marking)		35	SOT-23		›2SD2226K
BJV		Si-N	=2SD2351-V (SMD-Marking)		35(2mm)	SOT-323		›2SD2351
BJW		Si-N	=2SD2226K-W (SMD-Marking)		35	SOT-23		›2SD2226K
BJW		Si-N	=2SD2351-W (SMD-Marking)		35(2mm)	SOT-323		›2SD2351
BK		Si-P	=2SB1323 (SMD-Marking)		39	SOT-89		›2SB1323
BK		Si-N	=BCP 56-10 (SMD-Marking)		≈39°	SOT-223		›BCP 56
BK		Si-N	=BCX 56-10 (SMD-Marking)		39	SOT-89		›BCX 56
BK(p,s)		Si-P	=BCX 71K (SMD-Marking)		35	SOT-23		›BCX 71K
BK		Si-P+R	=XN 4114 (SMD-Marking)		46	SOT-163		›XN 4114
BK		Si-P+R	=XP 4114 (SMD-Marking)		46(2mm)	SOT-363		›XP 4114
BL		Si-P	=2SA1341 (SMD-Marking)		35	SOT-23		›2SA1341
BL		Si-P	=2SA1676 (SMD-Marking)		35(2mm)	SOT-323		›2SA1676
BL		Si-P	=2SB1324 (SMD-Marking)		39	SOT-89		›2SB1324
BL		Si-N	=BCP 56-16 (SMD-Marking)		≈39°	SOT-223		›BCP 56
BL		Si-N	=BCX 56-16 (SMD-Marking)		39	SOT-89		›BCX 56
BL		Si-P	=BCX 71L (SMD-Marking)		35	SOT-23		›BCX 71L

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER Fig.	International
BLF						
BLF 145	Phi	MOS-N-FET-e	VFET, SSB P, 65/20V, 3A, PEP=30W(28MHz/28V)	59(SDSG)	SOT-123	-
BLF 146	Phi	MOS-N-FET-e	VFET, SSB P, 65/25V, 7A, Gp>18dB(28MHz/28V)	59(SDSG)	SOT-121	-
BLF 147	Phi	MOS-N-FET-e	VFET, SSB P, 65/20V, 13A, PEP=150W(28MHz/28V)	59(SDSG)	SOT-121	-
BLF 175	Phi	MOS-N-FET-e	VFET, SSB P, 110/20V, 1,5A, PEP=8W(28MHz/50V)	59(SDSG)	SOT-123	-
BLF 177	Phi	MOS-N-FET-e	VFET, SSB P, 110/20V, 7A, PEP=150W(28MHz/50V)	59(SDSG)	SOT-121	-
BLF 241	Phi	MOS-N-FET-e	VFET, VHF, 65/20V, 0,5A, PQ=3W(175MHz/28V)	2a	TO-39	-
BLF 242	Phi	MOS-N-FET-e	VFET, VHF P, 65/20V, 0,5A, PQ=5W(175MHz/28V	59(SDSG)	SOT-123	-
BLF 244	Phi	MOS-N-FET-e	VFET, VHF P, 65/20V, 1,5A, PQ=15W(175MHz/28V)	59(SDSG)	SOT-123	-
BLF 245	Phi	MOS-N-FET-e	VFET, VHF P, 65/20V, 3A, PQ=30W(175MHz/28V)	59(SDSG)	SOT-123	-
BLF 246	Phi	MOS-N-FET-e	VFET, FM/VHF, 65/20V, 7A,PQ(CW-FM)=80W(108MHz/28V)	59(SDSG)	SOT-121	-
BLL		Si-N	=2SC4771K-L (SMD-Marking)	35	SOT-23	›2SC4771K
BLL		Si-N	=2SC4772-L (SMD-Marking)	35(2mm)	SOT-323	›2SC4772
BLM		Si-N	=2SC4771K-M (SMD-Marking)	35	SOT-23	›2SC4771K
BLM		Si-N	=2SC4772-M (SMD-Marking)	35(2mm)	SOT-323	›2SC4772
BLN		Si-N	=2SC4771K-N (SMD-Marking)	35	SOT-23	›2SC4771K
BLN		Si-N	=2SC4772-N (SMD-Marking)	35(2mm)	SOT-323	›2SC4772
BLP		Si-P	=2SB1561-P (SMD-Marking)	39	SOT-89	›2SB1561
BLP		Si-N	=2SC4771K-P (SMD-Marking)	35	SOT-23	›2SC4771K
BLP		Si-N	=2SC4772-P (SMD-Marking)	35(2mm)	SOT-323	›2SC4772
BLQ		Si-P	=2SB1561-Q (SMD-Marking)	39	SOT-89	›2SB1561
BLT						
BLT 50	Phi	Si-N	UHF Out, 20V, 0,5/1,5A, 2W, PQ=1,2W(470MHz/7,5V)	≈39°s	SOT-223	-
BLT 80	Phi	Si-N	UHF Out, 20V, 0,25/0,75A, 2W, PQ=0,8W(900MHz/7,5V)	≈39°s	SOT-223	-
BLT 81	Phi	Si-N	UHF Out, 20V, 0,5A, 2W, PQ=1,2W(900MHz/7,5V)	≈39°s	SOT-223	-
BLT 90/SL	Phi	Si-N	UHF Drv,Out, 20/10V, 0,25A, PQ=0,75W(900MHz/7,5V)	51r	SOT-172D	-
BLT 91/SL	Phi	Si-N	UHF Drv,Out, 20/10V, 0,5A, PQ=1,5W(900MHz/7,5V)	51r	SOT-172D	-
BLT 92/SL	Phi	Si-N	UHF Out, 20/10V, 1,2A, PQ=3W(900MHz/7,5V)	51r	SOT-122D	-
BLT 93/SL	Phi	Si-N	UHF Out, 20/10V, 1,2/3,6A, PQ=6W(900MHz/7,5V)	51r	SOT-122D	-
BLU						
BLU 10/12	Phi	Si-N	UHF P, 36/17V, 2A, PQ=10W(470MHz/12,5V)	57s	SOT-119	MRF 641
BLU 20/12	Phi	Si-N	UHF P, 36/16,5V, 4A, PQ=20W(470MHz/12,5V)	57s	SOT-119	MRF 641
BLU 30/12	Phi	Si-N	UHF P, 36/16,5V, 6/18A, PQ=30W(470MHz/12,5V)	57s	SOT-119	MRF 644
BLU 45/12	Phi	Si-N	UHF P, 36/16,5V, 9/27A, PQ=45W(470MHz/12,5V)	57s	SOT-119	MRF 648
BLU 50	Phi	Si-N	Dual, UHF P, 60/45V, 1,8A, PQ=30W(400MHz/28V)		SOT-161	-
BLU 51	Phi	Si-N	Dual, UHF P, 60/45V, 2,5A, PQ=45W(400MHz/28V)		SOT-161	-
BLU 52	Phi	Si-N	Dual, UHF P, 60/45V, 4A, PQ=60W(400MHz/28V)		SOT-161	-
BLU 53	Phi	Si-N	Dual, UHF P, 60/45V, 5A, PQ=100W(400MHz/28)	≈61/8Pin	SOT-161	-
BLU 56	Phi	Si-N	UHF Out, 36/16V, 0,2/0,6A, 2W, PQ=1W(470MHz/12,5V)	≈39°s	SOT-223	-
BLU 60/12	Phi	Si-N	UHF P, 36/16,5V, 12/36A, PQ=60W(470MHz/12,5V)	57s	SOT-119	MRF 648
BLU 86	Phi	Si-N	UHF Out, 32/16V, 0,2/0,6A, 2W, PQ=1W(900MHz/12,5V)	≈39°s	SOT-223	-
BLU 97	Phi	Si-N	UHF Drv,Out, 36/16V, 1,2/3,6A, PQ=7W(470MHz/12,5V)	55r	SOT-122	BLX 68, BLY 53
BLU 98	Phi	Si-N	UHF Drv,Out, 36/16V, 0,15A, PQ=0,5W(900MHz/12,5V)	25q	SOT-103	-
BLU 99	Phi	Si-N	UHF Drv,Out, 36/16V, 0,8/2,5A, PQ=4W(900MHz/12,5V) PQ=5W(470MHz/12,5V)	55r	SOT-122	-
BLV						
BLV 10	Phi	Si-N	VHF P, 36/18V, 1,5/4A, PQ=8W(175MHz/13,5V)	59r	SOT-123	MRF 221
BLV 11	Phi	Si-N	VHF P, 36/18V, 3/8A, PQ=15W(175MHz/13,5V)	59r	SOT-123	MRF 221...223
BLV 15/12	Phi	Si-N	VHF P, 36/18V, 3A, PQ=15W(175MHz/12,5V)	57s	SOT-119	MRF 215
BLV 20	Phi	Si-N	VHF P, 65/36V, 0,9/2,5A, PQ=8W(175MHz/28V)	59r	SOT-123	-
BLV 21	Phi	Si-N	VHF P, 65/36V, 1,75/5A, PQ=15W(175MHz/28V)	59r	SOT-123	-
BLV 25	Phi	Si-N	VHF P, 65/33V, 17,5/35A, PQ=175W(108MHz/28V)	57s	SOT-119	-
BLV 30	Phi	Si-N	VHF Drv,Out, 60/30V, 1,5/3,5A, PQ>1,5W(224MHz/25V)	55r	SOT-122	-
BLV 30/12	Phi	Si-N	VHF P, 36/18V, 6A, PQ=30W(175MHz/12,5V)	57s	SOT-119	MRF 216
BLV 31	Phi	Si-N	VHF P, 60/30V, 3/6A, PQ>5W(224MHz/25V)	55r	SOT-122	BLW 75
BLV 32 F	Phi	Si-N	VHF P, 60/30V, 4/12A, PQ>10W(224MHz/25V)	57s	SOT-160	-
BLV 33	Phi	Si-N	VHF P, 65/33V, 12,5/20A, PQ>19W(224MHz/25V)	55r	SOT-147	-
BLV 33 F	Phi	Si-N	VHF P, 65/33V, 12,5/20A, PQ>16W(224MHz/28V)	57s	SOT-119	-
BLV 34 F	Phi	Si-N	VHF P, 75/40V, 15/25A, PQ=130W(225MHz/35V)	57s	SOT-119	-
BLV 36	Phi	Si-N	Dual, VHF P, 65/33V, 10/20A, PQ=115W(224MHz/28)	≈61/8Pin	SOT-161	-
BLV 37	Phi	Si-N	Dual, VHF P, 70/40V, 10/30A, PQ=250W(108MHz/28V)	≈61/5Pin	SOT-179	-
BLV 38	Phi	Si-N	Dual, VHF P, 70/40V, 10/25A, PQ=225W(225MHz/35V)	≈61/5Pin	SOT-179	-
BLV 45/12	Phi	Si-N	VHF P, 36/16,5V, 9/27A, PQ=45W(175MHz/12,5V)	57s	SOT-119	MRF 243
BLV 57	Phi	Si-N	Dual, UHF P, 50/27V, 2/4A, PQ>6W(860MHz/25V)	≈61/8Pin	SOT-161	-
BLV 59	Phi	Si-N	UHF P, 50/27V, 3/9A, PQ=30W(860MHz/25V)	61s	SOT-171	-
BLV 75/12	Phi	Si-N	VHF P, 36/16,5V, 15/45A, PQ=75W(175MHz/12,5V)	57s	SOT-119	MRF 243, MRF 245
BLV 80/28	Phi	Si-N	VHF P, 65/33V, 8,5/17,5A, PQ=80W(175MHz/28V)	59r	SOT-121	BLW 78
BLV 90	Phi	Si-N	UHF Drv,Out, 36/16V, 0,2/0,6A, PQ=1W(900MHz/12,5V)	55r	SOT-172	MRF 838A
BLV 90/SL		Si-N	=BLV 90:	51r	SOT-172D	MRF 838
BLV 91	Phi	Si-N	UHF Drv,Out, 36/16V, 0,4/1,2A, PQ=2W(900MHz/12,5V)	55r	SOT-172	MRF 817
BLV 91/SL		Si-N	=BLV 91:	51r	SOT-172D	-
BLV 92	Phi	Si-N	UHF Drv,Out, 36/16V, 0,8/2,4A, PQ=4W(900MHz/12,5V)	61s	SOT-171	MRF 840
BLV 93	Phi	Si-N	UHF Drv,Out, 36/16V, 1,6/4,8A, PQ=8W(900MHz/12,5V)	61s	TO-171	MRF 840
BLV 94	Phi	Si-N	UHF P, 36/16V, 3/9A, PQ=15W(900MHz/12,5V)	61v	SOT-171	MRF 842
BLV 95	Phi	Si-N	UHF P, 36/16V, 5/15A, PQ=22W(900MHz/12,5V)	61v	SOT-171	MRF 844
BLV 97	Phi	Si-N	UHF P, 50/27V, 3/9A, PQ=30W(900MHz/24V)	61v	SOT-171	-
BLV 98	Phi	Si-N	UHF P, 50/27V, 1,5/4,5A, PQ=14W(900MHz/24V)	61v	SOT-171	-
BLV 99	Phi	Si-N	UHF Drv,Out, 50/27V, 0,2/0,6A, PQ=2W(900MHz/24V)	55r	SOT-172	BLX 91
BLW						
BLW 10	Tix	Si-N	VHF/UHF A,Drv, 55/30V, 0,4A, >500MHz	7a	TO-92	(BFS 23, 2N3866)[6]
BLW 11	Tix	Si-N	VHF/UHF A, 40/20V, 0,4A, >1,2GHz, Gp>11dB(40-216M)	2a	TO-39	BFR 36, BFW 16
BLW 12	Tix	Si-N	UHF Drv,Out, 36/18V, 0,4A, PQ>0,75W(470MHz/13V)	51r	TO-131	BLW 39, BLX 66
BLW 13	Tix	Si-N	UHF P, 36/18V, 2A, PQ>3,75W(470MHz/13V)	55r	TO-129	BLW 43, BLX 68, BLY 53
BLW 14	Tix	Si-N	UHF P, 36/18V, 2A, PQ>7W(470MHz/13V)	55r	TO-129	BLW 44, BLX 68, BLY 53B
BLW 15	Tix	Si-N	UHF P, 36/36V, 3A, PQ>12W(470MHz/13V)	55r	TO-129	BLX 69
BLW 16	Tix	Si-N	VHF Drv,Out, 36/18V, 0,5A, PQ>1,4W(175MHz/12V)	2a	TO-39	BFS 22, BFS 50...51, BLY 61, 2N4427, ++
BLW 17	Fer,Tix	Si-N	VHF Drv,Out, 36/18V, 0,5A, PQ>2W(175MHz/12V)	51r	TO-131	BLW 39, BLX 66
BLW 18	Tix	Si-N	VHF P, 36/18V, 2A, PQ>5W(175MHz/12V)	55r	TO-117	BLW 37, BLY 62, BLY 83, 2N5590, ++

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
BLW 19	Tix	Si-N	VHF P, 60/40V, 2A, PQ>8W(175MHz/13V)		55r	TO-117		BLW 37, BLY 83, MRF 212, 2N5590, ++
BLW 20	Tix	Si-N	VHF P, 36/18V, 5A, PQ>25W(175MHz/13V)		55r	TO-117		BLW 31, 2N6084
BLW 21	Tix	Si-N	HF P, 36/18V, 7A, 35MHz		55r	SOT-147		2N5708
BLW 22	Tix	Si-N	VHF A,Drv, 40/30V, 0,4A, 1000MHz		55r	TO-117		BFR 65, BFT 91, BLW 42, BLX 96
BLW 23	Tix	Si-N	VHF P, 55/40V, 2A, PQ>5W(175MHz/28V)		55r	TO-117		BLV 31, BLW 19, BLY 83
BLW 24	Tix	Si-N	VHF P, 60/40V, 2A, PQ>17W(175MHz/28V)		55r	TO-117		BLY 93, 2N5642
BLW 25	Tix	Si-N	VHF P, 65/35V, 5A, PQ>40W(175MHz/28V)		55r	SOT-48/2		BLY 94, 2N5643
BLW 26	Tix	Si-N	HF P (SSB), 36/18V, 8A, >50MHz, PQ>25W		59r	≈SOT-123		MRF 460, 2N5706, 2N5709, 2N5941
BLW 27	Tix	Si-N	HF L (SSB), 36/18V, 10A, >50MHz, PQ>35W		59r	≈SOT-123		MRF 460, 2N5709, 2N5942
BLW 29	Phi	Si-N	VHF P, 36/18V, 2,75/8A, PQ=15W(175MHz/13,5V)		55r	SOT-120		BLY 84, BLY 88, MRF 226, 2N6081
BLW 31	Phi	Si-N	VHF P, 36/18V, 6/15A, PQ=28W(175MHz/13,5V)		55r	SOT-120		BLW 20, 2N6084
BLW 32	Phi,Tix	Si-N	UHF P, 50/30V, 0,65/1A, PQ=0,58W(860MHz/25V)		55r	SOT-122		BLX 97
BLW 33	Phi	Si-N	UHF P, 50/30V, 1,25/1,9A, PQ=1,07W(860MHz/25V)		55r	SOT-122		BLW 98, BLX 98
BLW 34	Phi	Si-N	UHF P, 50/30V, 2,25/3,5A, PQ=1,9W(860MHz/25V)		55r	SOT-122		BLW 98, BLX 98
BLW 35	Aeg	Si-N	VHF P, 39/17V, 1,7/2,5A, PQ>7,5W(175MHz/12V)		49a	TO-60		BLY 36, BLY 58, BLY 79, 2N3927
BLW 36	Aeg	Si-N	VHF P, 39/17V, 3,5/5A, PQ>15,5W(175MHz/12V)		49a	TO-60		BLY 36
BLW 37	Aeg	Si-N	=BLW 35:		55r	SOT-48		BLW 19, BLY 62, BLY 83, MRF 212, 2N5590
BLW 38	Aeg	Si-N	=BLW 36:		55r	SOT-48		BLW 20, BLY 63, BLY 84, MRF 238, 2N6083
BLW 39	Fer	Si-N	UHF Drv,Out, 50/28V, 0,5A, PQ>2W(175MHz)		51r	TO-131		BLW 17, BLX 66
BLW 42	Aeg	Si-N	UHF P, 50/25V, 0,7/2,1A, PQ>1,1W(470MHz/12V)		55r	SOT-48		BLX 92, 2N5944
BLW 43	Aeg	Si-N	UHF P, 50/25V, 1/3A, PQ>3,5W(470MHz/12V)		55r	SOT-48		BLU 97, BLW 80, BLX 68, BLX 93, BLY 53
BLW 44	Aeg	Si-N	UHF P, 50/25V, 2/6A, PQ>8W(470MHz)		55r	SOT-48		BLW 14, BLW 81, BLX 94, 2N5946
BLW 45	Tho	Si-N	UHF Drv,Out, 25/20V, 0,15A, PQ=0,2W(1GHz)		55r			BLV 90, MRF 838A
BLW 46	Tho	Si-N	=BLW 45:		51r			MRF 816, MRF 838
BLW 47	Tho	Si-N	UHF Drv,Out, 25/20V, 0,2A, PQ=0,5W(1GHz)		55r			BLV 90, MRF 838A
BLW 48	Tho	Si-N	=BLW 47:		51r			MRF 816, MRF 838
BLW 50 F	Phi	Si-N	AM SSB P, 110/55V, 2,5/7,5A, PEP=17W(28MHz/45V)		59r	SOT-123		-
BLW 60	Phi	Si-N	AM...VHF P, 36/18V, 8/20A, PQ=45W(175MHz/12,5V)		55r	SOT-56		BLY 90
BLW 60 C	Phi	Si-N	=BLY 60: 9/22A		55r	SOT-120		-
BLW 64	Phi	Si-N	VHF P, 60/30V, 4/12A, PQ>15W(224MHz/25V)		55r	SOT-56		BLW 75
BLW 65	Sol	Si-N	LF,HF Drv, 40/40V, -/5A, 6W(Tc=25°), 80MHz		2a	TO-5		BUX 34, BUX 49, BUY 41, BUY 80, ++
BLW 66	Sol	Si-N	=BLW 65: 60/60V		2a	TO-5		BUX 34, BUX 49, BUY 41, BUY 80, ++
BLW 67	Sol	Si-N	=BLW 65: 80/80V		2a	TO-5		BUX 34, BUX 49, BUY 41, BUY 80, ++
BLW 68	Sol	Si-N	=BLW 65: 100/100V		2a	TO-5		BUX 34, BUX 49, BUY 41, BUY 80, ++
BLW 69	Sol	Si-N	=BLW 65: 120/120V		2a	TO-5		BUX 34, BUX 49, BUY 41, BUY 80, ++
BLW 70	Sol	Si-N	=BLW 65: 140/140V		2a	TO-5		BU 125S, BUX 50, BUY 49, BUY 80, ++
BLW 71	Sol	Si-N	=BLW 65: 160/160V		2a	TO-5		BU 125S, BUX 50, BUY 49
BLW 72	Sol	Si-N	=BLW 65: 180/180V		2a	TO-5		BU 125S, BUX 50, BUY 49
BLW 73	Sol	Si-N	=BLW 65: 200/200V		2a	TO-5		BU 125S, BUX 50, BUY 49
BLW 75	Phi	Si-N	VHF P, 60/32V, 4/12A, PQ>14W(225MHz/25V)		55r	SOT-56		BLW 64
BLW 76	Phi	Si-N	AM/FM P, 70/35V, 8/20A, PQ=80W(108MHz/28V)		59r	SOT-121		-
BLW 77	Phi	Si-N	AM/FM P, 70/35V, 12/30A, PQ=130W(87,5MHz/28V)		59r	SOT-121		BLW 96
BLW 78	Phi	Si-N	AM...VHF P, 70/35V, 10/25A, PQ=100W(150MHz/28V)		59r	SOT-121		-
BLW 79	Phi	Si-N	UHF P, 36/17V, 0,5/1,5A, PQ=2W(470MHz/12,5V)		55r	SOT-122		BLX 67, BLY 38, 2N5945
BLW 80	Phi	Si-N	UHF P, 36/17V, 1/3A, PQ=4W(470MHz/12,5V)		55r	SOT-122		BLU 97, BLW 43, BLX 68, BLY 53
BLW 81	Phi	Si-N	UHF P, 36/17V, 2,5/7,5A, PQ=10W(470MHz/12,5V)		55r	SOT-122		BLW 15, BLW 44, BLX 69, 2N5946
BLW 82	Phi	Si-N	UHF P, 36/17V, 7/18A, PQ=30W(470MHz/12,5V)		57s	SOT-119		BLU 30/12, MRF 646
BLW 83	Phi	Si-N	AM SSB P, 65/36V, 3/9A, PEP=30W(28MHz)		59r	SOT-123		2N5941
BLW 84	Phi	Si-N	VHF P, 65/36V, 3/9A, PQ=25W(175MHz/28V)		59r	SOT-123		BLW 86, MRF 314
BLW 85	Phi	Si-N	AM...VHF P, 36/18V, 9/22A, PQ=45W(175MHz/12,5V)		59r	SOT-123		-
BLW 86	Phi	Si-N	VHF P, 65/36V, 4/12A, PQ=45W(175MHz/28V)		59r	SOT-123		MRF 315
BLW 87	Phi	Si-N	VHF P, 36/18V, 6/12A, PQ=25W(175MHz/13,5V)		59r	SOT-123		MRF 224
BLW 89	Phi	Si-N	UHF P, 60/30V, 0,32/1A, PQ=2W(470MHz/28V)		55r	SOT-122		BFT 91, BLW 92, BLY 76, MRF 5174
BLW 90	Phi	Si-N	UHF P, 60/30V, 0,62/2A, PQ=4W(470MHz/28V)		55r	SOT-122		BLW 93, BLY 37
BLW 91	Phi	Si-N	UHF P, 60/30V, 1,5/3,5A, PQ=10W(470MHz/28V)		55r	SOT-122		BLW 94, BLX 94, MRF 323
BLW 92	Aeg	Si-N	UHF P, 60/30V, 0,7/2,1A, PQ>1,5W(470MHz)		55r	SOT-48		BLW 90, BLX 92
BLW 93	Aeg	Si-N	UHF P, 60/30V, 1/3A, PQ>4,5W(470MHz)		55r	SOT-48		BLW 91, BLX 93, MRF 321
BLW 94	Phi	Si-N	UHF P, 60/30V, 2/6A, PQ>15W(470MHz)		55r	SOT-48		BLX 94, MRF 323
BLW 95	Phi	Si-N	AM SSB P, 110/53V, 8/20A, PEP=160W(28MHz/50V)		59r	SOT-121		BLW 96
BLW 96	Phi	Si-N	AM/FM P, 110/55V, 12/40A, PEP=200W(108MHz/50V)		59r	SOT-121		-
BLW 97	Phi	Si-N	AM SSB P, 65/33V, 15/50A, PEP=175W(28MHz/28V)		59r	SOT-121		-
BLW 98	Phi	Si-N	UHF P, 50/27V, 2/4A, PQ=4,4W(860MHz/25V)		55r	SOT-122		BLX 98, 2N4431
BLW 99	Phi	Si-N	AM SSB P, 36/17V, 18/55A, PEP=80W(28MHz/12,5V)		59r	SOT-121		MRF 421, MRF 454
BLX								
BLX 10	Tra	Si-N	LF P, 125/80V, 2A, 11W(Tc=50°), >10MHz, <1/-µs		2a	TO-5		BU 125S, BUX 49...50, BUY 41
BLX 11	Tra	Si-N	=BLX 10: 145/100V		2a	TO-5		BU 125S, BUX 49...50, BUY 49
BLX 12	Tra	Si-N	=BLX 10: 170/120V		2a	TO-5		BU 125S, BUX 50...51, BUY 49
BLX 13(C)	Phi	Si-N	AM/FM P, 65/36V, 3/6A, PQ=25W(70MHz/28V) BLX 13C: PEP=25W(28MHz/28V)		55r	SOT-56 SOT-120		-
BLX 14	Phi	Si-N	AM/FM P, 85/36V, 4/12A, PQ=50W(70MHz/28V)		≈55r	SOT-55		-
BLX 15	Phi	Si-N	AM/FM P, 110/53V, 6,5/20A, PQ=150W(108MHz/50V)		≈55r	SOT-55		-
BLX 16	Tra	Si-N	LF P, 125/80V, 5A, 15W(Tc=50°), >10MHz, <1,5/-µs		2a	TO-5		BU 125, BUX 34, BUY 47...48, BUY 80...81
BLX 17	Tra	Si-N	=BLX 16: 145/100V		2a	TO-5		BUY 47...48, BUY 68, BUY 80...81
BLX 18	Tra	Si-N	=BLX 16: 170/120V		2a	TO-5		BUY 48
BLX 19	Tra	Si-N	LF P, 125/80V, 5A, 75W(Tc=50°), >10MHz, <2/-µs		49m	TO-61		2N1724, 2N5387...5389
BLX 20	Tra	Si-N	=BLX 19: 145/100V		49m	TO-61		2N1724, 2N5387...5389
BLX 21	Tra	Si-N	=BLX 19: 170/120V		49m	TO-61		2N1724A, 2N5387
BLX 22	Tra	Si-N	LF P, 125/80V, 10A, 60W(Tc=50°), >10MHz, <2/-µs		49m	TO-59		(2N5542)[6]
BLX 23	Tra	Si-N	=BLX 22: 145/100V		49m	TO-59		(2N5542)[6]
BLX 24	Tra	Si-N	=BLX 22: 170/120V		49m	TO-59		(2N5542)[6]
BLX 25	Tra	Si-N	LF P, 125/80V, 30A, 150W(Tc=50°), >10MHz, <2/-µs		49m	TO-63		2N2825, 2N6324...6325
BLX 26	Tra	Si-N	=BLX 25: 145/100V		49m	TO-63		2N2825, 2N6324...6325
BLX 27	Tra	Si-N	=BLX 25: 170/120V		49m	TO-63		2N6324...6325
BLX 28	Tra	Si-N	LF P, 125/80V, 40A, 187W(Tc=50°), >10MHz, <2/-µs		49m	TO-63		2N2825, 2N6324...6325
BLX 29	Tra	Si-N	=BLX 28: 145/100V		49m	TO-63		2N2825, 2N6324...6325
BLX 30	Tra	Si-N	=BLX 28: 170/120V		49m	TO-63		2N6324...6325
BLX 31	Tra	Si-N	LF P, 125/80V, 60A, 300W(Tc=50°), >10MHz, 500/-ns		49m	TO-63		2N6278...6281
BLX 32	Tra	Si-N	=BLX 31: 145/100V		49m	TO-63		2N6278...6281
BLX 33	Tra	Si-N	=BLX 31: 170/120V		49m	TO-63		-
BLX 34	Tra	Si-N	LF P, 125/80V, 80A, 300W(Tc=50°), >10MHz, <2/-µs		49m	TO-114		2N6309...6311
BLX 35	Tra	Si-N	=BLX 34: 145/100V		49m	TO-114		2N6310...6311
BLX 36	Tra	Si-N	=BLX 34: 170/120V		49m	TO-114		2N6311

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER Fig.	International
BLX 37	Phi	Si-N	UHF, 35/25V, 0,4A, 3GHz			-
BLX 38	Phi	Si-N	UHF, 30/16V, 0,8A, 3GHz			-
BLX 39	Phi	Si-N	VHF P, 65/36V, 4/12A, PQ=45W(170MHz/28V)	55r	SOT-120	BLW 25, MRF 315A, 2N5643
BLX 40	Tra	Si-P	LF P, 80/80V, 2A, 11W(Tc=50°), >20MHz, <1/-µs	2a	TO-5	BUY 90, 2N6190…6193
BLX 41	Tra	Si-P	=BLX 40: 100/100V	2a	TO-5	BUY 90, 2N6192…6193
BLX 42	Tra	Si-P	=BLX 40: 120/120V	2a	TO-5	BUY 90
BLX 46	Tra	Si-P	LF P, 80/80V, 5A, 15W(Tc=50°), >20MHz, <1,5/-µs	2a	TO-5	BUY 90, 2N6190…6193
BLX 47	Tra	Si-P	=BLX 46: 100/100V	2a	TO-5	BUY 90, 2N6192…6193
BLX 48	Tra	Si-P	=BLX 46: 120/120V	2a	TO-5	BUY 90
BLX 49	Tra	Si-P	LF P, 80/80V, 5A, 45W(Tc=50°), >20MHz, <1,5/-µs	49m	TO-59	2N5003, 2N5005, 2N5286…87, 2N6182…85
BLX 50	Tra	Si-P	=BLX 49: 100/100V	49m	TO-59	2N5003, 2N5005, 2N5286…87, 2N6184…85
BLX 51	Tra	Si-P	=BLX 49: 120/120V	49m	TO-59	2N5286…5287
BLX 52	Tra	Si-P	LF P, 80/80V, 10A, 60W(Tc=50°), >20MHz, <1,5/-µs	49m	TO-59	2N6182…6185, 2N6186…6189
BLX 53	Tra	Si-P	=BLX 52: 100/100V	49m	TO-59#	2N6184…6185, 2N6188…6189
BLX 54	Tra	Si-P	=BLX 52: 120/120V	49m	TO-59	(2N5290…5291)[6]
BLX 55	Tra	Si-P	LF P, 80/80V, 30A, 150W(Tc=50°), >20MHz, <1,5/-µs	49m	TO-61	(2N6380…6382)[6]
BLX 56	Tra	Si-P	=BLX 55: 100/100V	49m	TO-61	(2N6380…6382)[6]
BLX 57	Tra	Si-P	=BLX 55: 120/120V	49m	TO-61	(2N6381…6382)[6]
BLX 58	Tra	Si-P	LF P, 80/80V, 40A, 187W(Tc=50°), >20MHz, <1,5/-µs	49m	TO-63	2N6380…6382
BLX 59	Tra	Si-P	=BLX 58: 100/100V	49m	TO-63	2N6380…6382
BLX 60	Tra	Si-P	=BLX 58: 120/120V	49m	TO-63	2N6381…6382
BLX 61	Tra	Si-P	LF P, 80/80V, 60A, 300W(Tc=50°), >20MHz, <1,5/-µs	49m	TO-63	2N6061, 2N6063, 2N6380…6382
BLX 62	Tra	Si-P	=BLX 61: 100/100V	49m	TO-63	2N6061, 2N6063, 2N6380…6382
BLX 63	Tra	Si-P	=BLX 61: 120/120V	49m	TO-63	2N6381…6382
BLX 65	Phi,Tix	Si-N	UHF Drv,Out, 36/18V, 0,7/2A, PQ=2W(470MHz/12,5V)	2a	TO-39	2N5913
BLX 65 E,ES		Si-N	=BLX 65:	2e(E=case)	TO-39	-
BLX 66	Phi,Tix	Si-N	UHF P, 36/18V, 0,7/2A, PQ=2,5W(470MHz/12,5V)	51r		-
BLX 67	Phi,Tix	Si-N	UHF P, 36/18V, 0,7/2A, PQ=3W(470MHz/13,8V)	55r	SOT-48/3	BLW 43, BLW 80, 2N5945
BLX 68	Phi,Tix	Si-N	UHF P, 36/18V, 1/4A, PQ=7,8W(470MHz/13,8V)	55r	SOT-48/3	BLU 97, BLY 53
BLX 69(A)	Phi	Si-N	UHF P, 36/18V, 3,5/10A, PQ=17W(470MHz/12,5V)	55r	SOT-48/2	BLW 15
BLX 70	Tra	Si-N	LF P, -/225V, -/20A, 100W(Tc=45°), >10MHz	49m	TO-63	2N6325
BLX 71	Tra	Si-N	=BLX 70: -/250V	49m	TO-63	2N6325
BLX 72	Tra	Si-N	=BLX 70: -/300V	49m	TO-63	2N6325
BLX 73	Tra	Si-N	=BLX 70: -/375V	49m	TO-63	-
BLX 74	Tra	Si-N	LF P, -/225V, -/10A, 50W(Tc=45°), >10MHz	49m	TO-61	2N5388…5389, 2N5540
BLX 75	Tra	Si-N	=BLX 74: -/250V	49m	TO-61	2N5388…5389, 2N5540
BLX 76	Tra	Si-N	=BLX 74: -/300V	49m	TO-61	2N5389, 2N5540
BLX 77	Tra	Si-N	=BLX 74: -/375V	49m	TO-61	-
BLX 78	Tra	Si-N	LF P, -/225V, -/5A, 30W(Tc=45°)	49m	TO-59	-
BLX 79	Tra	Si-N	=BLX 79: -/250V	49m	TO-59	-
BLX 80	Tra	Si-N	=BLX 79: -/300V	49m	TO-59	-
BLX 81	Tra	Si-N	=BLX 79: -/375V	49m	TO-59	-
BLX 82	Tra	Si-P	LF P, 60/60V, 20A, 150W(Tc=50°), >20MHz, <1/-µs	23a	TO-3	BD 250A, BD 367, BD 746A, 2N5883…5884
BLX 83	Tra	Si-P	=BLX 82: 80/80V	23a	TO-3	BD 250B, BD 369, BD 746B, 2N5884
BLX 84	Tra	Si-P	=BLX 82: 100/100	23a	TO-3	BD 250C, BD 746C, MJ 4502
BLX 85	Tra	Si-N	LF P, 60/60V, 20A, 150W(Tc=50°), >10MHz, <2/-µs	23a	TO-3	BD 249A, BD 366, BD 745A, 2N5885…5886
BLX 86	Tra	Si-N	=BLX 85: 80/80V	23a	TO-3	BD 249B, BD 368, BD 745B, 2N5886
BLX 87	Tra	Si-N	=BLX 85: 100/100V	23a	TO-3	BD 249C, BD 745C, MJ 802
BLX 88	Tho	Si-N	VHF A,Drv, 50/30V, 0,1A, >600MHz	2a	TO-39	BFS 23, BFW 16…17, BFX 33, 2N3866
BLX 89	Fer	Si-N	VHF A,Drv, 50/28V, 0,5A, 900MHz	2a	TO-39	BFS 23, BFX 33, BFX 55, 2N3866
BLX 91(A)	Phi	Si-N	UHF Drv,Out, 65/33V, 0,4/0,8A, PQ=1W(470MHz/28V)	55r	SOT-48/3	BFT 91, BLW 89, BLY 76
BLX 91 CB		Si-N	=BLX 91:	55t	SOT-48/3	-
BLX 92(A)	Phi	Si-N	UHF Drv,Out, 65/33V, 0,7/2A, PQ=2,5W(470MHz/28V)	55r	SOT-48/3	BLW 90, BLW 92, BLY 37, MRF 5174
BLX 93(A)	Phi	Si-N	UHF Drv,Out, 65/33V, 1/3A, PQ=7W(470MHz/28V)	55r	SOT-48/3	BLW 91, MRF 321
BLX 94(A,C)	Phi	Si-N	UHF P, 65/30V, 2/6A, PQ=20W(470MHz/28V) BLX 94(A): Fig. SOT-48/2, BLX 84C: Fig. SOT-122	55r	SOT-48/2	BLW 94, MRF 323
BLX 95(A)	Phi	Si-N	UHF P, 65/30V, 3/10A, PQ=40W(470MHz/28V)	55r	SOT-56	2N6104…6105
BLX 96	Phi	Si-N	UHF Drv,Out, 40/27V, 0,4/1A, PQ=0,6W(860MHz/25V)	55r	SOT-48/3	BLW 32, BLX 91, 2N4429
BLX 97	Phi	Si-N	UHF Drv,Out, 40/27V, 0,8/2A, PQ=1,1W(860MHz/25V)	55r	SOT-48/3	BLW 33, 2N4430
BLX 98	Phi	Si-N	UHF P, 40/27V, 2/4A, PQ=4W(860MHz/25V)	55r	SOT-48/2	BLW 98, 2N4431
BLY						
BLY 10	Itt	Si-N	HF P, 40/20V, 0,5A, 10W(Tc=45°), >50MHz	23a	TO-3	-
BLY 11	Itt	Si-N	=BLY 10: >100MHz	23a	TO-3	-
BLY 12	Itt	Si-N	HF P, 60/30V, 1,5/5A, 25W, >60MHz	23a	TO-3	-
BLY 14	Itt	Si-N	VHF Drv,Out, 80/55V, 1A, PQ=3,6W(180MHz/40V)	49a		BLY 60
BLY 15	Itt	Si-N	HF P, 90/64V, 2A, 15W, 200MHz, Gp>10dB(70MHz)	23a	TO-3	-
BLY 15 A	Itt	Si-N	HF P, 64/64V, 2A, 11,5W, 180MHz	22a	SOT-9	-
BLY 16	Itt	Si-N	HF P, 64/64V, 1,5A, 11W, 250MHz, Gp=10dB(200MHz)	22a	TO-66	-
BLY 17(A,C)	Phi	Si-N	HF P, 100V, 10A, PQ=40W(30MHz/40V)	38a	TO-36	-
BLY 20	Phi	Si-N	VHF P, 45/30V, 1/2A, PQ=6W(180MHz)	49a	TO-60	BLY 57, BLY 60, 2N3632, 2N3926
BLY 21	Phi	Si-N	VHF P, 70/45V, 1/2A, PQ=12W(180MHz)	49a	TO-60	BLY 60, 2N3632
BLY 22	Sie	Si-N	VHF P, 65/40V, 1,5A, 500MHz, PQ>7,5W(175MHz)	49a	TO-60	BLY 60, 2N3632
BLY 23	Sie	Si-N	VHF P, 65/40V, 3A, 400MHzt, PQ>13,5W(175MHz)	49a	TO-60	BLY 60, 2N3632
BLY 25	Sgs	Si-N	VHF P, 120/80V, 5A, 195MHz, 500/-ns	49a	TO-59	2N4116, 2N5002, 2N5004
BLY 26	Sgs	Si-N	VHF P, 100/60V, 5A, 135MHz, 500/-ns	49a	TO-59	2N4115, 2N5002, 2N5004
BLY 27	Tho	Si-N	VHF P, 80/80V, 1A, >150MHz, PQ>4W(250MHz)	49a	TO-60	BLY 59…60, 2N3375, 2N3632
BLY 28	Tho	Si-N	VHF P, 80/80V, 1A, >125MHz, PQ>4W(125MHz)	49a	TO-60	BLY 59…60, 2N3375, 2N3632
BLY 29	Sgs	Si-N	HF/S P, 100/80V, 2A, 46MHz, <300/1500ns	49a	TO-59	2N2892…93, 2N4075…76, 2N4998, 2N5000
BLY 30	Sgs	Si-N	=BLY 29: 50MHz	49a	TO-59	2N2892…93, 2N4075…76, 2N4998, 2N5000
BLY 33	Phi,Tix	Si-N	VHF Drv,Out, 66/33V, 0,5/1,5A, PQ=3W(175MHz/28V)	2a	TO-39	BFS 23, BFW 47, 2N3553
BLY 34	Phi,Tix	Si-N	VHF Drv,Out, 40/20V, 0,5/1,5A, PQ=3W(175MHz/13,8V)	2a	TO-39	BFS 22, BFW 46, 2N3924
BLY 35	Phi,Tix	Si-N	VHF P, 66/33V, 2,5/7,5A, PQ=13W(175MHz/24V)	49a	TO-60	BLY 60, 2N3632
BLY 36	Phi,Tix	Si-N	VHF P, 40/20V, 2,5/7,5A, PQ=13W(175MHz/13,8V)	49a	TO-60	BLY 58, 2N3927
BLY 37	Phi,Tix	Si-N	UHF P, 65/36V, 0,75/2,5A, PQ=6W(470MHz/28V)	55r	SOT-36	BLW 93, BLX 93, MRF 321
BLY 38	Phi,Tix	Si-N	UHF P, 36/18V, 0,5/1,5A, PQ=2W(470MHz/13,8V)	55r	SOT-36	BLW 43, BLW 79, BLX 67, 2N5945
BLY 39	Fer	Si-N	UHF P, 60/35V, 2A, 800MHz, PQ>7W(470MHz)	55r	TO-129	BLW 91, BLX 93, MRF 321
BLY 40	Tho	Si-N	HF P, 100/100V, 10A, 125W, >40MHz		≈TO-81	=2N5072
BLY 47	Tix	Si-N	S P, 100V, 3/5A, 40W, 300/2000ns, hFE=30…100	23a	TO-3	BDY 24
BLY 47 A		Si-N	=BLY 47:	22a	TO-66	2N6077…6079, 2N6233…6235
BLY 48	Tix	Si-N	=BLY 47: hFE=60…120	23a	TO-3	BDY 24
BLY 48 A		Si-N	=BLY 48:	22a	TO-66	2N6077…6079, 2N6233…6235
BLY 49	Tix	Si-N	=BLY 47: 250V	23a	TO-3	BDY 26

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BLY 49 A		Si-N	=BLY 49:		22a	TO-66			2N6077…6079, 2N6233…6235
BLY 50	Tix	Si-N	=BLY 47: 250V, hFE=60…120		23a	TO-3			BDY 26
BLY 50 A		Si-N	=BLY 50:		22a	TO-66			2N6077…6079, 2N6233…6235
BLY 53	Phi	Si-N	UHF P, 36/18V, 1,3/4A, PQ=6W(470MHz/13,8V)		55r	SOT-36			BLU 97, BLW 14, BLX 68
BLY 53 A	Phi	Si-N	UHF P, 36/18V, 1/4A, PQ=7,8W(470MHz/13,8V)		55r	SOT-48/3			BLU 97, BLW 14, BLX 68
BLY 53 B	Fer	Si-N	UHF P, 36/18V, 2A, PQ>8,3W(470MHz/13,8V)		55r	TO-129			BLW 14, BLW 44, 2N5946
BLY 55	Phi	Si-N	VHF P, 40/20V, 1/3A, PQ=4W(175MHz/13,8V)		49a	TO-60			BLY 57, BLY 78, 2N3926
BLY 57	Mot,Phi,Tix	Si-N	VHF P, 36/18V, 1/3A, PQ>7W(175MHz/13,5V)		49a	TO-60			BLY 78, =2N3926
BLY 58	Mot,Phi,Tix	Si-N	VHF P, 36/18V, 1,5/4,5A, PQ>12W(175MHz/13,5V)		49a	TO-60			BLY 79, =2N3927
BLY 59	Mot,Phi,Tix	Si-N	VHF P, 65/40V, 0,5/1,5A, PQ>7,5W(100MHz/28V)		49a	TO-60			=2N3375
BLY 60	Mot,Phi,Tix	Si-N	VHF P, 65/40V, 1/3A, PQ>13,5W(175MHz/28V)		49a	TO-60			=2N3632
BLY 61	Tix	Si-N	VHF Drv,Out, 36/18V, 0,5A, PQ>1W(175MHz/13V)		2a	TO-39			BFR 98, BFS 22, BFS 51, BLW 16, 2N4427
BLY 62	Tix	Si-N	VHF P, 36/18V, 2A, PQ>5W(175MHz/13V)		55r	TO-117			BLW 18…19, BLW 37, MRF 212, 2N5590
BLY 63	Tix	Si-N	VHF P, 36/18V, 5A, PQ>15W(175MHz/13V)		55r	TO-117			BLW 20, BLW 31, BLW 38, 2N6084
BLY 64	Sgs	Si-N	HF P, 80/60V, 5A, 50W, >60MHz		49m	TO-59			2N5002, 2N5004
BLY 65	Sgs	Si-P	HF P, 80/60V, 5A, 50W, >60MHz		49m	TO-59			2N5003, 2N5005
BLY 66(A,B)	Sgs	Si-N	HF P, 100/80V, 2A, 30W, >50MHz		49a	TO-59			2N4998, 2N5000
BLY 67(A,B)	Sgs	Si-P	HF P, 100/80V, 2A, 30W, >50MHz		49a	TO-59			2N4999, 2N5001
BLY 68	Sgs	Si-N	LF,HF P, 100/80V, 3A, 25W, 100MHz		23a	TO-3			BDY 90…91, 2SC2681, 2SC2706, 2SC2837
BLY 70	Sgs	Si-N	LF,HF P, 100/80V, 5A, 33W, 70MHz		23a	TO-3			BDY 90…91, 2SC2681, 2SC2706, 2SC2837
BLY 72	Sgs	Si-N	LF,HF P, 80/60V, 10A, 100W, >30MHz		49a	TO-61			2N5006, 2N5008, 2N5288…5289
BLY 74	Sgs,Tix	Si-N	VHF P, 65/40V, 0,5/1,5A, PQ>3W(400MHz/28V)		49a	TO-60			-
BLY 76	Phi,Tix	Si-N	UHF Drv,Out, 65/36V, 0,3/1A, PQ=2W(470MHz/28V)		55r	SOT-36			BFT 91, BLW 89, BLW 92, BLX 92
BLY 78	Aeg,Tix	Si-N	VHF P, 40/20V, 1A, PQ>4,7W(175MHz/12V)		49a	TO-60			BLY 57, 2N3926
BLY 79	Aeg,Tix	Si-N	VHF P, 40/20V, 2A, PQ>11W(175MHz/12V)		49a	TO-60			BLY 58, 2N3927
BLY 80	Aeg	Si-N	VHF P, 40/20V, 1A, PQ>4W(175MHz/12V)						-
BLY 81	Aeg	Si-N	VHF P, 40/20V, 2A, PQ>11W(175MHz/12V)						-
BLY 82	Tho	Si-N	HF P, 80/80V, 10A, 125W, >40MHz			=TO-81			BLY 40, 2N5072
BLY 83	Phi,Tix	Si-N	VHF P, 66/33V, 2,5/7,5A, PQ>7W(175MHz/13,8V)		55r	SOT-48/3			BLW 19, MRF 212, 2N5590
BLY 84	Phi,Tix	Si-N	VHF P, 40/20V, 2,5/7,5A, PQ>13W(175MHz/13,8V)		55r	SOT-48/3			BLW 29, BLY 88, MRF 226, 2N6081
BLY 85	Phi,Tix	Si-N	VHF P, 40/20V, 1/3A, PQ>4W(175MHz/13,8V)		55r	SOT-48/3			BLY 87, 2N6080
BLY 86	Sgs	Si-N	TV-HA, 300/300V, 0,4A, 10W, 60MHz		22a	TO-66			2N3739, 2SC1929, 2SC2022, 2SC2354,
BLY 87(A,C)	Phi,Tix	Si-N	VHF P, 36/18V, 1,25/3,75A, PQ=8W(175MHz/12,5V) BLY 87(A): Fig. SOT-48/2, BLY 87C: Fig. SOT-120		55r	SOT-48/2			BLW 19, BLW 37, MRF 212, 2N5590
BLY 88(A,C,T)	Phi,Tix	Si-N	VHF P, 36/18V, 2,5/7,5A, PQ=15W(175MHz/12,5V) BLY88(A): Fig. SOT-48/2, C: SOT-120, T: TO-117		55r	SOT-48/2			BLW 29, BLY 84, MRF 226, 2N6081
BLY 89(A,C)	Phi,Tix	Si-N	VHF P, 36/18V, 3,5/10A, PQ=25W(175MHz/13,5V) BLY89(A): Fig. SOT-48/2, BLY89C: Fig. SOT-120		55r	SOT-48/2			MRF 209, MRF 238, 2N5591, 2N6082…83
BLY 90	Phi	Si-N	VHF P, 36/18V, 8/20A, PQ=50W(175MHz/12,5V)		=55r	SOT-55			-
BLY 91(A,C)	Phi,Tix	Si-N	VHF P, 65/36V, 0,75A, PQ=8W(175MHz/28V) BLY91(A): Fig. SOT-48/2, BLY91C: Fig. SOT-120		55r	SOT-48/2			BLY 98, 2N5641
BLY 92(A,C)	Phi,Tix	Si-N	VHF P, 65/36V, 1,5/4,5A, PQ=15W(175MHz/28V) BLY92(A): Fig. SOT-48/2, BLY92C: Fig. SOT-120		55r	SOT-48/2			BLW 24, BLY 93
BLY 93(A,C)	Phi,Tix	Si-N	VHF P, 65/36V, 2/6A, PQ=25W(175MHz/28V) BLY93: SOT-56, A: 3/9A, SOT-56, C: SOT-120		55r	SOT-56			BLW 24
BLY 94	Phi	Si-N	VHF P, 65/36V, 6/12A, PQ=50W(175MHz/28V)		=55r	SOT-55			BLW 25, 2N5643
BLY 95	Aeg	Si-N	VHF P, 55/31V, 1A, >400MHz						-
BLY 96	Aeg	Si-N	VHF P, 55/31V, 2A, >500MHz						-
BLY 97	Phi,Tix	Si-N	VHF P, 60/33V, 1/3A, PQ>4W(175MHz/24V)		55r	SOT-48/3			BLY 91, BLY 98, 2N5641
BLY 98	Phi	Si-N	VHF P, 60/33V, 1A, PQ=7W(175MHz)		55r	SOT-48/3			BLY 91, BLY 97, 2N5641
BLY 99	Phi	Si-N	VHF P, 30/15V, 0,5A, PQ>1W(470MHz)		2a	TO-39			BFS 50, BLX 65, MRF 629, 2N3948
BM....BO									
BM		Si-P	=2SB1325 (SMD-Marking)		39	SOT-89			›2SB1325
BM		Si-N	=BCP 55-16 (SMD-Marking)		=39°	SOT-223			›BCP 55
BM		Si-N	=BCX 55-16 (SMD-Marking)		39	SOT-89			›BCX 55
BM(p,s)		Si-P	=BSS 63 (SMD-Marking)		35	SOT-23			›BSS 63
BM 339		KOP-IC	=LM 339						›LM 339
BMQ		Si-N	=2SC4713K-Q (SMD-Marking)		35	SOT-23			›2SC4713K
BMQ		Si-N	=2SC4774-Q (SMD-Marking)		35(2mm)	SOT-323			›2SC4774
BMR		Si-N	=2SC4713K-R (SMD-Marking)		35	SOT-23			›2SC4713K
BMR		Si-N	=2SC4774-R (SMD-Marking)		35(2mm)	SOT-323			›2SC4774
BMS		Si-N	=2SC4713K-S (SMD-Marking)		35	SOT-23			›2SC4713K
BMS		Si-N	=2SC4774-S (SMD-Marking)		35(2mm)	SOT-323			›2SC4774
BN		Si-P	=2SB1394 (SMD-Marking)		39	SOT-89			›2SB1394
BN(s)		Si-P	=BCW 61FN (SMD-Marking)		35	SOT-23			›BCW 61FN
BN 1 A3Q…L4Z	Nec	Si-P+R	=AN 1A3Q…L4Z:	{BA1…	40c	(SST)			-
BN 2 A3Q	Nec	Si-P+R	S, Rb=1k, Rbe=10kΩ, 25/25V, 0,1/0,2A, 0,25W hi-hFE>220	{BA2A3Q	40c	(SST)			-
BN 2 A4M	Nec	Si-P+R	=BN 2A3Q: Rb=10k, Rbe=10kΩ, hi-hFE>220	{BA2A4M	40c	(SST)			-
BN 2 A4P	Nec	Si-P+R	=BN 2A3Q: Rb=10k, Rbe=47kΩ, hi-hFE>350	{BA2A4P	40c	(SST)			-
BN 2 A4Z	Nec	Si-P+R	=BN 2A3Q: Rb=10k, Rbe=-, hi-hFE>400	{BA2A4Z	40c	(SST)			-
BN 2 F4M	Nec	Si-P+R	=BN 2A3Q: Rb=22k, Rbe=22kΩ, hi-hFE>300	{BA2F4M	40c	(SST)			-
BN 2 F4N	Nec	Si-P+R	=BN 2A3Q: Rb=22k, Rbe=47kΩ, hi-hFE>350	{BA2F4N	40c	(SST)			-
BN 2 F4Z	Nec	Si-P+R	=BN 2A3Q: Rb=22k, Rbe=-, hi-hFE>400	{BA2F4Z	40c	(SST)			-
BN 2 L3M	Nec	Si-P+R	=BN 2A3Q: Rb=Rbe=4,7kΩ, hi-hFE>150	{BA2L3M	40c	(SST)			-
BN 2 L3N	Nec	Si-P+R	=BN 2A3Q: Rb=4,7k, Rbe=10kΩ, hi-hFE>220	{BA2L3N	40c	(SST)			-
BN 2 L3Z	Nec	Si-P+R	=BN 2A3Q: Rb=4,7k, Rbe=-, hi-hFE>400	{BA2L3Z	40c	(SST)			-
BN 2 L4L	Nec	Si-P+R	=BN 2A3Q: Rb=47k, Rbe=22kΩ, hi-hFE>300	{BA2L4L	40c	(SST)			-
BN 2 L4M	Nec	Si-P+R	=BN 2A3Q: Rb=47k, Rbe=47kΩ, hi-hFE>350	{BA2L4M	40c	(SST)			-
BN 2 L4Z	Nec	Si-P+R	=BN 2A3Q: Rb=47k, Rbe=-, hi-hFE>400	{BA2L4Z	40c	(SST)			-
BN 3 L4Z	Nec	Si-P+R	Rb=47kΩ, int. Emitter-Di, 20/20V, 20mA, 0,25W	{BA3L4Z	40c	(SST)			-
BO		Si-P	=2SA1200-O (SMD-Marking)		39	SOT-89			›2SA1200
BO		Si-P	=2SB1396 (SMD-Marking)		39	SOT-89			›2SB1396
BO		Si-P	=BCW 61RA (SMD-Marking)		35	SOT-23			›BCW 61RA
BO		Si-P	=KTA1660-O (SMD-Marking)		39	SOT-89			›KTA 1660
BO 12	Tho	Si-Di	Uni, 100V, 0,25/1A, Uf=1V(0,2A)		31a	DO-7	BA 159	31a	BA 157…159, BY 204/4, BY 208/600, ++
BO 22	Tho	Si-Di	=BO 12: 200V		31a	DO-7	BA 159	31a	BA 157…159, BY 204/4, BY 208/600, ++
BO 42	Tho	Si-Di	=BO 12: 400V		31a	DO-7	BA 159	31a	BA 157…159, BY 204/4, BY 208/6, ++
BO 62	Tho	Si-Di	=BO 12: 600V		31a	DO-7	BA 159	31a	BA 158…159, BY 204/8, BY 208/600, ++
BO 82	Tho	Si-Di	=BO 12: 800V		31a	DO-7	BA 159	31a	BA 159, BY 204/8, BY 208/800, ++
BO 102	Tho	Si-Di	=BO 12: 1000V		31a	DO-7	BA 159	31a	BA 159, BY 204/10, BY 208/1000, ++

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BOD 1-04....40(L,R)	Bbc	Trigger-Di	Ub=400...4000V,Ib=1mA,Itsm=200A		26b				-
BP...BQ									
BP		Si-P	=2SB1397 (SMD-Marking)		39	SOT-89			›2SB1397
BP		Si-P	=BCW 61RB (SMD-Marking)		35	SOT-23			›BCW 61RB
BP 1 A3M...L3N	Nec	Si-P+R	=AP 1A3M...L3N:	{BB1...	40c	(SST)			-
BP 50 M05	Rhm	Hybrid-IC	DC-DC Converter, 5V, 0,25A		≈9-SIP				-
BP 50 M12	Rhm	Hybrid-IC	DC-DC Converter, 12V, 0,25A		≈9-SIP				-
BP 51 L05	Rhm	Hybrid-IC	DC-DC Converter, 5V, 0,05A		≈9-SIP				-
BP 51 L12	Rhm	Hybrid-IC	DC-DC Converter, 12V, 0,05A		≈9-SIP				-
BP 3002	Rhm	Hybrid-IC	Telecom, Telefonapparat/Telephone Unit			(56x38x14)			-
BP 3003	Rhm	Hybrid-IC	Telecom, Telefonapparat/Telephone Unit			(56x38x14)			-
BP 3004	Rhm	Hybrid-IC	Telecom, Telefonapparat/Telephone Unit			(48x38x14)			-
BP 3005	Rhm	Hybrid-IC	Telecom, Telefonapparat/Telephone Unit			(48x38x14)			-
BP 3008	Rhm	Hybrid-IC	Telecom, Telefon Set f. FAX			(49x37x16)			-
BP 3009	Rhm	Hybrid-IC	Telecom, Telefon Set f. FAX			(49x37x16)			-
BP 3303	Rhm	Hybrid-IC	Telecom, Telefon Set f. FAX, Multifunction			(73x35x16)			-
BP 3304	Rhm	Hybrid-IC	Telecom, Telefon Set f. FAX, Multifunction			(73x35x16)			-
BP 3501	Rhm	Hybrid-IC	Telecom, Speakerphone Processor, Power Amp.		≈20-SIP				-
BP 5005	Rhm	Hybrid-IC	DC-DC Converter, 5V, 0,25A		≈9-SIP				-
BP 5201	Rhm	Hybrid-IC	DC-DC Converter, 5V, 0,2A, 24V Input		≈7-SIP				-
BP 5401	Rhm	Hybrid-IC	DC-DC Converter, +5V/1A, +12V/1A, -12V/0,1A			(50x50x20)			-
BPW		Opto							
BPX		Opto							
BPY		Opto							
BQ		Si-P	=2SB1218A-Q (SMD-Marking)		35(2mm)	SOT-323			›2SB1218A
BQ		Si-P	=2SB1627-Q (SMD-Marking)		≈35	(T Mini)			›2SB1627
BQ		Si-P	=2SB709A-Q (SMD-Marking)		35	SOT-23			›2SB709A
BQ		Si-P	=2SB766A-Q (SMD-Marking)		39	SOT-89			›2SB766A
BQ		Si-N	=2SC2412-BQ (SMD-Marking)		≈35	(MMT)			›2SC2412
BQ		Si-N	=2SC2412K-Q (SMD-Marking)		35	SOT-23			›2SC2412K
BQ		Si-N	=2SC4081-Q (SMD-Marking)		35(2mm)	SOT-323			›2SC4081
BR									
BR		Si-P	=2SB1218A-R (SMD-Marking)		35(2mm)	SOT-323			›2SB1218A
BR		Si-P	=2SB1627-R (SMD-Marking)		≈35	(T Mini)			›2SB1627
BR		Si-P	=2SB709A-R (SMD-Marking)		35	SOT-23			›2SB709A
BR		Si-P	=2SB766A-R (SMD-Marking)		39	SOT-89			›2SB766A
BR		Si-N	=2SC2412-BR (SMD-Marking)		≈35	(MMT)			›2SC2412
BR		Si-N	=2SC2412K-R (SMD-Marking)		35	SOT-23			›2SC2412K
BR		Si-N	=2SC4081-R (SMD-Marking)		35(2mm)	SOT-323			›2SC4081
BR		Si-P	=BCW 61RC (SMD-Marking)		35	SOT-23			›BCW 61RC
BR		Si-N+R	=XN 4214 (SMD-Marking)		46	SOT-163			›XN 4214
BR		Si-N+R	=XP 4214 (SMD-Marking)		46(2mm)	SOT-363			›XP 4214
BR 1		Si-P	=BSP 30 (SMD-Marking)		≈39°	SOT-223			›BSP 30
BR 1		Si-P	=BSR 30 (SMD-Marking)		39	SOT-89			›BSR 30
BR 2		Si-P	=BSP 31 (SMD-Marking)		≈39°	SOT-223			›BSP 31
BR 2		Si-P	=BSR 31 (SMD-Marking)		39	SOT-89			›BSR 31
BR 3		Si-P	=BSP 32 (SMD-Marking)		≈39°	SOT-223			›BSP 32
BR 3		Si-P	=BSR 32 (SMD-Marking)		39	SOT-89			›BSR 32
BR 4		Si-P	=BSP 33 (SMD-Marking)		≈39°	SOT-223			›BSP 33
BR 4		Si-P	=BSR 33 (SMD-Marking)		39	SOT-89			›BSR 33
BR 24 C01A	Rhm	EEPROM-IC	Serial, 1024 (128 x 8)Bit, Ucc= 2,7...5,5V, I²C-Bus		8-DIP				-
BR 24 C02	Rhm	EEPROM-IC	Serial, 2048 (256 x 8)Bit, Ucc= 2,7...5,5V, I²C-Bus		8-DIP				-
BR 24 C04	Rhm	EEPROM-IC	Serial, 4096 (512 x 8)Bit, Ucc= 2,7...5,5V, I²C-Bus		8-DIP				-
BR 24 C01F...04F		EEPROM-IC	=BR 24C01...04: SMD		8-MDIP				-
BR 28 C16 A-150	Rhm	EEPROM-IC	CMOS, 2048 x 8 Bit, Ucc=4,5...5,5V, 150ns		24-DIP				...28C16...
BR 28 C64	Rhm	EEPROM-IC	CMOS, 8k x 8 Bit, Ucc=4,5...5,5V		28-DIP				...28C64...
BR 46 C15	Rhm	EEPROM-IC	CMOS, 2048 x 8 Bit		24-DIP				-
BR 93 C46	Rhm	EEPROM-IC	CMOS, Serial, 1024 (64 x 16)Bit, Ucc= 4,5...5,5V		8-DIP				-
BR 93 C56A	Rhm	EEPROM-IC	CMOS, Serial, 2048(128W x 16)Bit, Ucc=4,5...5,5V		8-DIP				-
BR 93 C56AF	Rhm	EEPROM-IC	=BR 93C56A: SMD		8-MDIP				-
BR 93 CS46	Rhm	EEPROM-IC	CMOS, Serial, 1024 (64 x 16)Bit, 5V		8-DIP				-
BR 93 CS46F	Rhm	EEPROM-IC	=BR 93CS46: SMD		8-MDIP				-
BR 93 LC46	Rhm	EEPROM-IC	CMOS, Serial, 1024(64 x 16)Bit, Ucc=2,7...5,5V		8-DIP				-
BR 93 LC46A	Rhm	EEPROM-IC	=BR 93LC46: Ucc=4,5...5,5V		8-DIP				-
BR 93 LC46AF	Rhm	EEPROM-IC	=BR 93LC46A: SMD		8-MDIP				-
BR 93 LC46F	Rhm	EEPROM-IC	=BR 93LC46: SMD		8-MDIP				-
BR 93 LC56	Rhm	EEPROM-IC	CMOS, Serial, 2048(128 x 16)Bit, Ucc=2,7...5,5V		8-DIP				-
BR 93 LC56A	Rhm	EEPROM-IC	=BR 93LC56: Ucc=4,5...5,5V		8-DIP				-
BR 93 LC56AF	Rhm	EEPROM-IC	=BR 93LC56A: SMD		8-MDIP				-
BR 93 LC56F	Rhm	EEPROM-IC	=BR 93LC56: SMD		8-MDIP				-
BR 93 LC66	Rhm	EEPROM-IC	CMOS, Serial, 4096(256 x 16)Bit, Ucc=2,7...5,5V		8-DIP				-
BR 93 LC66A	Rhm	EEPROM-IC	=BR 93LC66: Ucc=4,5...5,5V		8-DIP				-
BR 93 LC66ARF	Rhm	EEPROM-IC	=BR 93LC66A: SMD		8-MDIP				-
BR 93 LC66RF	Rhm	EEPROM-IC	=BR 93LC66: SMD		8-MDIP				-
BR 93 LL46	Rhm	EEPROM-IC	CMOS, Serial, 1024 (64 x 16)Bit, Ucc= 1,8...4V		8-DIP				-
BR 93 LL46F		EEPROM-IC	=BR 93LL46: SMD		8-MDIP				-
BR 100(/03)	Phi	Diac	Ub=28...36V, Ib<0,1mA, Itsm=2A, BR100/03: DO-35		31a	DO-14	BR 100	31a	1N5761, N 413M, D 3202Y, D 0201YR
BR 101	Phi	Tetrode	Tetrode, 50V, 0,175/0,5A, 300MHz, Ih=0,1...1mA		5g	TO-72			BRY 39, BRY 62
BR 103	Sie,Tag	F-Thy	30V, 0,8A≈, Igt/Ih<0,2/<2mA, <10µs		7a	TO-92	(BRX 49)	7a	BRX 44...49, TAG 60A...Y, TAG 62A...Y, ++
BR 103 X	Tag	F-Thy	=BR 203: <6µs		2a	TO-39	TAG 103 X	2a	TAG 64A...Y, TAG 103X
BR 203	Tag	F-Thy	30V, 1A≈, Igt/Ih<0,2/<2mA, <10µs		2a	TO-39	TAG 103 X	2a	TAG 64A...Y, TAG 103X
BR 210-100...280	Phi	Si-Di	Breakover-Di(Diac,TAZ), 6A, 400W(1ms)		17(A1-A2)	TO-220			-
BR 211-100...280	Phi	Si-Di	Breakover-Di(Diac,TAZ), 50W(1ms)		31	SOD-84			-
BR 213-100...280	Phi	Si-Di	=BR 210-...: Dual		17(A1A2A3)	TO-220			-
BR 216	Phi	Si-Di	Brakover-Di(Diac,TAZ), Dual, 110W(1ms)		17(A1A2A3)	TO-220			-
BR 220-100...280	Phi	Si-Di	=BR 210-...: Dual		17(A1A2A3)	TO-220			-
BR 303	Sie,Tag	F-Thy	30V, 1A≈, Igt/Ih<2/<5mA, <13µs		14e	TO-126	(TAG 103 X)	2a	BR 403, TAG 66A...Y
BR 403	Sie	F-Thy	=BR 303:		13e	TO-202	(TAG 103 X)	2a	BR 303, TAG 66A...Y
BR 2804 A	Rhm	EEPROM-IC	512 x 8 Bit, 5V		24-DIP				...2804...
BR 2816 A	Rhm	EEPROM-IC	2048 x 8 Bit, 5V		24-DIP				...2816...
BR 2864 A	Rhm	EEPROM-IC	8192 x 8 Bit, 5V		28-DIP				...2864...

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.		International
BR 2865 A	Rhm	EEPROM-IC	8192 x 8 Bit, 5V		28-DIP					...2865...
BR 6116	Rhm	CMOS-sRAM-IC	hi-speed, 2048 x 8 Bit		24-DIP					... 6116...
BR 6216 A	Rhm	CMOS-sRAM-IC	16k(2048 x 8)Bit, <150ns, TTL Inp/Out, 0...+70°		24-DIP					-
BR 6216 B-10LL	Rhm	CMOS-sRAM-IC	16k(2048 x 8)Bit, <100ns, TTL Inp/Out, 0...+70°		24-SDIP					-
BR 6264 A	Rhm	CMOS-sRAM-IC	hi-speed, 8192 x 8 Bit		28-DIP					... 6164...
BR 6264 P	Rhm	CMOS-sRAM-IC	hi-speed, 8192 x 8 Bit		28-DIP					... 6164...
BR 6265	Rhm	CMOS-sRAM-IC	64k(8k x 8)Bit, <120ns, TTL Inp/Out, 0...+70°		28-DIP					-
BR 6265 A-10LL	Rhm	CMOS-sRAM-IC	64k(8k x 8)Bit, <100ns, TTL Inp/Out, 0...+70°		28-DIP					-
BR 6265 AF-10LL	Rhm	CMOS-sRAM-IC	=BR 6265A-10LL: SMD		28-MDIP					-
BR 9021 A	Rhm	EEPROM-IC	CMOS, ser, 2048 (128 x 16)Bit, Ucc=4,5...5,5V		8-DIP					-
BR 9021 AF	Rhm	EEPROM-IC	=BR 9021A: SMD		8-MDIP					-
BR 9021 B	Rhm	EEPROM-IC	CMOS, ser, 2048 (128 x 16)Bit, Ucc=2,7...5,5V		8-DIP					-
BR 9021 BF	Rhm	EEPROM-IC	=BR 9021B: SMD		8-MDIP					-
BR 9040	Rhm	EEPROM-IC	Serial, 4096 (256 x 16)Bit, Ucc= 2,7...5,5V		8-DIP					-
BR 9040 F		EEPROM-IC	=BR 9040: SMD		8-MDIP					-
BR 9041 A	Rhm	EEPROM-IC	Serial, 4096 (256 x 16)Bit, Ucc= 4,5...5,5V		8-DIP					-
BR 9041 ARF		EEPROM-IC	=BR 9041: SMD		8-MDIP					-
BR 62256	Rhm	sRAM-IC	CMOS, lo-power, 32k x 8 Bit		28-DIP					-
BRT 11...13	Sie	LIN-IC	SITAC AC-Switch (FET + Thy + Photo-Detector)		6-DIP	SOT-90				-
BRT 21...23	Sie	LIN-IC	SITAC AC-Switch (FET + Thy + Photo-Detector)		6-DIP	SOT-90				-
BRX										
BRX 44	Mot,Phi,++	F-Thy	30V, 0,8A~, Igt/Ih<0,2/<5mA, 8µs		7a	TO-92	BRX 49	7a		BRX 50...56, BRY 55S/30...800
BRX 45	Mot,Phi,++	F-Thy	=BRX 44: 60V		7a	TO-92	BRX 49	7a		BRX 51...56, BRY 55S/60...800
BRX 46	Mot,Phi,++	F-Thy	=BRX 44: 100V		7a	TO-92	BRX 49	7a		BRX 51...56, BRY 55S/100...800
BRX 47	Mot,Phi,++	F-Thy	=BRX 44: 200V		7a	TO-92	BRX 49	7a		BRX 52...56, BRY 55S/200...800
BRX 48	Mot,Phi,++	F-Thy	=BRX 44: 300V		7a	TO-92	BRX 49	7a		BRX 53...56, BRY 55S/300...800
BRX 49	Mot,Phi,++	F-Thy	=BRX 44: 400V		7a	TO-92	BRX 49	7a		BRY 54...56, BRY 55S/400...800S
BRX 50	Tag	F-Thy	50V, 0,6A(Tc=55°), Igt/Ih<0,2/<5mA		7a	TO-92	BRX 49	7a		BRX 45...49, BRY 55S/60...800
BRX 51	Tag	F-Thy	=BRX 50: 100V		7a	TO-92	BRX 49	7a		BRX 46...49, BRY 55S/100...800
BRX 52	Tag	F-Thy	=BRX 50: 200V		7a	TO-92	BRX 49	7a		BRX 47...49, BRY 55S/200...800
BRX 53	Tag	F-Thy	=BRX 50: 300V		7a	TO-92	BRX 49	7a		BRX 48...49, BRY 55S/300...800
BRX 54	Tag	F-Thy	=BRX 50: 400V		7a	TO-92	BRX 49	7a		BRX 49, BRY 55S/400...800
BRX 55	Tag	F-Thy	=BRX 50: 500V		7a	TO-92				BRY 55S/500...800
BRX 56	Tag	F-Thy	=BRX 50: 600V		7a	TO-92				BRY 55S/600...800
BRX 60	Tag	F-Thy	50V, 2,6A(Tc=100°), Igt/Ih<0,2/<5mA		14e	TO-126				TAG 66A...F, BR 303
BRX 61	Tag	F-Thy	=BRX 60: 100V		14e	TO-126				TAG 66A
BRX 62	Tag	F-Thy	=BRX 60: 200V		14e	TO-126				-
BRX 63	Tag	F-Thy	=BRX 60: 300V		14e	TO-126				-
BRX 64	Tag	F-Thy	=BRX 60: 400V		14e	TO-126				-
BRX 65	Tag	F-Thy	=BRX 60: 500V		14e	TO-126				-
BRX 66	Tag	F-Thy	=BRX 60: 600V		14e	TO-126				-
BRX 70-03...-50	Tho	50Hz-Thy	30...500V, 0,5A(Ta=55°), Igt<0,2mA		7a	TO-92	BRX 49	7a		BRX 45...49, BRX 50...56, BRY 55/...,++
BRX 71-03...-50	Tho	50Hz-Thy	30...500V, 0,5A(Ta=55°), Igt<0,2mA		7e	TO-92	BRX 49	7a		BRX 45...49, BRX 50...56, BRY 55/...,++
BRX 72-03...-50	Tho	50Hz-Thy	30...500V, 0,6A(Ta=55°), Igt<0,2mA		≈30e	TO-237	(BRX 49)	7a		(BRX 45...49, BRX 50...56, BRY 55/...,++)
BRX 73-03...-50	Tho	50Hz-Thy	30...500V, 0,6A(Ta=55°), Igt<0,2mA		≈30a	TO-237	(BRX 49)	7a		(BRX 45...49, BRX 50...56, BRY 55/...,++)
BRX 78-03...-50	Tho	Triac	30...500V, Igt<10mA		7l	TO-92				MAC 94-..., MAC 95-..., Z 106-...
BRX 79-03...-50	Tho	Triac	30...500V, Igt<10mA		≈30	TO-237				(MAC 94-..., MAC 95-..., Z 106-...)
BRY										
BRY 10....18	Aeg	Thy			5(AKGaGk)	TO-12				-
BRY 20	Sie	Tetrode	40V, 0,5A, 7µs		5(AKGaGk)	TO-12				-
BRY 21	Sie	Tetrode	=BRY 20: 80V		2a	TO-5				-
BRY 23	Sgs	F-Thy	100V, 2,2A(Tc=85°), Igt/Ih<0,2/<2,5mA, <22µs		2a	TO-5				-
BRY 24	Sgs	F-Thy	=BRY 23: 200V		2a	TO-5				-
BRY 25	Sgs	F-Thy	=BRY 23: 300V		2a	TO-5				-
BRY 26	Sgs	F-Thy	=BRY 23: 400V		2a	TO-5				-
BRY 28	Sgs	F-Thy	100V, 2,2A(Tc=85°), Igt/Ih<15/<25mA		2a	TO-5				TAG 2,5S-...
BRY 29	Sgs	F-Thy	=BRY 28: 200V		2a	TO-5				TAG 2,5S-...
BRY 30	Sgs	F-Thy	=BRY 28: 300V		2a	TO-5				TAG 2,5S-...
BRY 31	Sgs	F-Thy	=BRY 28: 400V		2a	TO-5				TAG 2,5S-...
BRY 32	Sgs	F-Thy	50V, 1A(Tc=25°), Igt/Ih<0,5/<2mA, <15µs		2a	TO-46	BRX 49	7a		BRX 50...56
BRY 33	Sgs	F-Thy	=BRY 32: 100V		2a	TO-46	BRX 49	7a		BRX 51...56
BRY 34	Sgs	F-Thy	=BRY 32: 200V		2a	TO-46	BRX 49	7a		BRX 52...56
BRY 35	Sgs	F-Thy	100V, 1,3A(Tc=80°), Igt/Ih<0,1/<1mA, <22µs		2a	TO-5				-
BRY 36	Sgs	F-Thy	=BRY 35: 200V		2a	TO-5				-
BRY 37	Sgs	F-Thy	=BRY 35: 300V		2a	TO-5				-
BRY 39(P,S,T)	Mot,Phi	Tetrode	70V, 0,25A		5g	TO-72				(BRY 21)[6]
BRY 40	Fer	Si-Di	PNPN-Diode, 300V		31a	DO-7				-
BRY 41-50....-600	Ssc	Triac	50...600V, 1A(Tc=75°), Igt/Ih<25/25mA		2m	TO-5				T 2303A...M, T 2306A...F
BRY 42	Itt	50Hz-Thy	250V, 3A(Tc=90°), Igt/Ih<25/<25mA, <20µs							-
BRY 43	Itt	50Hz-Thy	=BRY 42: 400V							-
BRY 44	Itt	50Hz-Thy	=BRY 42: 500V							-
BRY 45/50...600	Ssc	Triac	50...600V, 3A(Tc=75°), Igt/Ih<50/<25mA		2m	TO-5				-
BRY 46	Itt	Tetrode	15/20V, 0,05A(Tc=85°), Igt/Ih<0,2/<1mA		6(GkKGaA)	≈SOT-103				BR 101, BRY 39, MAS 32, MAS 39
BRY 49	Aeg	Tetrode	30V, 0,3A(Tc=85°), <5µs		5h	TO-72				BRY 39, (BRY 20...21)[6]
BRY 50	Aeg	Tetrode	=BRY 49: 70V		5h	TO-72				BRY 39, (BRY 21)[6]
BRY 51	Aeg	Tetrode	=BRY 49: 120V		5h	TO-72				-
BRY 52-50...-600	Ssc	Triac	50...600V, 6A(Tc=75°), Igt/Ih<50/<50mA		2m	TO-5				(BT 158/..., T 2806B...M, T 2856A...M,++)[4]
BRY 53	Fer	Si-Di	PNPN-Di, 90...125V, 0,04A, Itsm=5A, Igt=0,5mA		31a	DO-7				-
BRY 54/30....600(T)	Ssc	50Hz-Thy	30...600V, 2,5A~(Tc=70°), Igt/Ih<20/<25mA, tq=50µs		2a	TO-5				TAG 2,5-..., TAG 611-...
			BRY54...T: 2,5A~(85°), Igt/Ih<20/<20mA							
BRY 55/30....800(M)	Mot,Sie,Tho	Thy	30...800V, 0,8A~, Igt/Ih<0,2/<5mA, 20µs, M: 15µs		7a	TO-92	BRX 49 (400V!)	7a		BRY 58/..., TAG 70D...S, TAG 72D...S, ++
BRY 55/30S....800S	Tho	F-Thy	=BRY 55/...(M): <6µs		7a	TO-92				-
BRY 56 A	Phi,Sie	PUT	70V, 0,175A, 0,5W, Ip<0,22µA, Iv>2µA, 80ns		7c	TO-92				-
BRY 56 B		PUT	=BRY 56A: Ip<1,1µA, Iv>10µA		7c	TO-92				-
BRY 56 C		PUT	=BRY 56A: Ip<5µA, Iv>50µA		7c	TO-92				-
BRY 57	Fer	Si-Di	PNPN-Di, 90...125V, 0,04A, Itsm=6A, Igt<1mA		31a	DO-41				-
BRY 58/30....800	Tho	Thy	=BRY 55/...:		2a	TO-46	BRX 49 (400V!)	7a		›BRY 55/...
BRY 59 A....B	Tix	Thy	A=30V, B=60V, 0,43A(Ta=25°), Igt<0,1mA		7n	TO-92				TAG 06A...YY, TIC 44...47, TIC 60...64, ++
BRY 61	Phi	PUT	SMD, 70V, 0,175A, Ip<5µA, Iv>30µA, 80ns		35b	SOT-23				-
BRY 62	Phi	Tetrode	SMD, Tetrode, 70V, 0,175A, Ih<1mA, <5µs		44(GkKAGa)	SOT-143				-
BRY 70/200...800	Sie	Thy	200...800V, 0,5A, Igt<10mA		7	TO-92				-

Original	Fabric.	Constr.	Info	{Compl. Fig.		JAEGER	Fig.	International
BRY 71/200…800	Sie	Thy	200…800V, 0,5A, Igt<0,2mA	7	TO-92	BRX 49 (400V!)	7a	BRY 55/…, TAG 70…, TAG 72…,++
BS								
BS		Si-P	=2SA1669 (SMD-Marking)	35	SOT-23			›2SA1669
BS		Si-P	=2SB1218A-S (SMD-Marking)	35(2mm)	SOT-323			›2SB1218A
BS		Si-P	=2SB1627-S (SMD-Marking)	≈35	(T Mini)			›2SB1627
BS		Si-P	=2SB709A-S (SMD-Marking)	35	SOT-23			›2SB709A
BS		Si-P	=2SB766A-S (SMD-Marking)	39	SOT-89			›2SB766A
BS		Si-N	=2SC2412-BS (SMD-Marking)	≈35	(MMT)			›2SC2412
BS		Si-N	=2SC2412K-S (SMD-Marking)	35	SOT-23			›2SC2412K
BS		Si-N	=2SC4081-S (SMD-Marking)	35(2mm)	SOT-323			›2SC4081
BS		Si-P	=BCW 61RD (SMD-Marking)	35	SOT-23			›BCW 61RD
BS 1		Si-P	=BSP 60 (SMD-Marking)	≈39°	SOT-223			›BSP 60
BS 1		Si-P-Darl	=BST 60 (SMD-Marking)	39	SOT-89			›BST 60
BS 2		Si-P	=BSP 61 (SMD-Marking)	≈39°	SOT-223			›BSP 61
BS 2		Si-P-Darl	=BST 61 (SMD-Marking)	39	SOT-89			›BST 61
BS 3		Si-P	=BSP 62 (SMD-Marking)	≈39°	SOT-223			›BSP 62
BS 3		Si-P-Darl	=BST 62 (SMD-Marking)	39	SOT-89			›BST 62
BS 6-01A…07A	Bbc	Triac	100…700V, 6A(Tc=85°), Igt<50mA	21l	TO-48			TW6N…C, BS8…A, TW8N…C, BS10…A, ++
BS 6-01B…07B		Triac	=BS 6-…A:	29l	TO-203			TW6N…H, BS8…B, TW8N…H, BS10…B, ++
BS 7-02A…06A	Bbc	Triac	200…600V, 6A(Tc=80°), Igt<60mA	17j	TO-220			MAC216…,SC141…,T 2801…,TXC10K…M, ++
BS 08 A	Mit	SBS	175mA, Ub=7…9V, Is<0,2mA, Ih<1,5mA, Igt=10…200µA	7m(Thy)	TO-92			2N4992
BS 8-01A…07A	Bbc	Triac	100…700V, 8A(Tc=85°), Igt<50mA	21l	TO-48			TW8N…C, BS10…A, TW10M…C, TW12N…C, ++
BS 8-01B…07B		Triac	=BS 8-…A:	29l	TO-203			TW8N…H, BS10…B, TW10M…H, TW12N…H, ++
BS 9-02A…06A	Bbc	Triac	200…600V, 8A(Tc=80°), Igt<60mA	17j	TO-220			T 2802…,MAC222…, TIC226…, TXD10K…,++
BS 10-01A…07A	Bbc	Triac	100…700V, 10A(Tg=85°), Igt<50mA	21l	TO-48			TW10N…C, TW12N…C, TW18N…, TW25N…
BS 10-01B…07B		Triac	=BS 10-…A:	29l	TO-203			TW10N…H, TW12N…H, T6401…
BS 107	Phi,Sie,++	MOS-N-FET-e	VFET,200/14V, 0,13/0,52A, 1W, <26Ω(0,12A), 13/27ns	7a	TO-92			BS 108, BSS 89, BSS 101, BST 74, ++
BS 107 A	Mot,Phi,++	MOS-N-FET-e	=BS 107: 200/20V, on<6,4Ω(0,25A)	7a	TO-92			›BS 107
BS 107 P,PT	Fer	MOS-N-FET-e	=BS 107:	40e	≈TO-92			›BS 107
BS 108	Itt,Phi	MOS-N-FET-e	VFET, 200/20V, 0,25/1A, 1W, on<8Ω(0,1A), 5/20ns	7a	TO-92			BSN 205, BSS 88, BSS 89, BST 74
BS 109	Itt	MOS-N-FET-e	VFET, 300/25V, 0,15A, 0,83W, on<20Ω(0,1A), 15/40ns	7a	TO-92			BSS 124
BS 110	Fer	Si-N	SMD, S, 20/12V, -/0,2A, >400MHz, <12/18ns	35d(2mm)	SOT-323			2SC4755, (BSV 52, 2SC1621, 2SC3578)[6]
BS 112	Itt	MOS-N-FET-e	VFET, 170/20V, 0,2A, 0,83W, on<10Ω(0,1A), 5/50ns	7a	TO-92			BS 107…108, BSS 101, BS 189, BSS 89, ++
BS 170	Phi,Sie,++	MOS-N-FET-e	VFET, 60/14V, 0,3A, 0,83W, on<5Ω(0,2A), 13/29ns	7a	TO-92			BSS 296, BST 70, 2SK422…423
BS 170 P	Fer	MOS-N-FET-e	=BS 170: 60/20V, 0,27A, 0,625W	40e	≈TO-92			›BS 170
BS 189	Itt	MOS-N-FET-e	VFET, 200/20V, 0,2A, 0,83W, on<7Ω(0,1A), 5/50ns	7c	TO-92			BS 108, BSS 89, BST 74, BSS 88, ++
BS 192	Itt	MOS-P-FET-e	VFET, 200/20V, 0,18A, 0,83W, on<14Ω(0,1A), 5/35ns	7c	TO-92			BS 208, BSS 92, BSP 204
BS 208	Itt,Phi,Six	MOS-P-FET-e	VFET, 200/20V, 0,2/0,6A, 0,83W, <14Ω(0,2A), 5/20ns	7a	TO-92			BS 192, BS 209, BSS 92, BSP 204
BS 209	Itt	MOS-P-FET-e	VFET, 300/20V, 0,12A, 0,83W, on<30Ω(0,1A), 15/40ns	7a	TO-92			-
BS 212	Itt	MOS-P-FET-e	VFET, 170/20V, 0,2A, 0,83W, on14Ω(0,1A), 5/35ns	7a	TO-92			BS 192, BS 208, BSP 204
BS 250	Itt,Phi	MOS-P-FET-e	VFET, 45/20V, 0,25/0,5A, 0,83W, <14Ω(0,2A), 5/25ns	7a	TO-92			BST 100
BSC….BSD								
BSC 52	Ucp	Si-N	SMD, 40V, 0,1A, 300MHz	Chip	TO-122			-
BSD 10	Phi	MOS-N-FET-d	SS, Chopper, 15/10/15V, 50mA, on<50Ω, 1/5ns	5k	TO-72			-
BSD 12	Phi	MOS-N-FET-d	=BSD 10: 25/20/15V	5k	TO-72			-
BSD 20	Phi	MOS-N-FET-d	=BSD 10: SMD	44(GDSSub)	SOT-143			-
BSD 22	Phi	MOS-N-FET-d	=BSD 12: SMD	44(GDSSub)	SOT-143			-
BSD 212	Phi	MOS-N-FET-e	S, Chopper, sym, 40/10/40V, 50mA, on<70Ω, 1/5ns	5k	TO-72			-
BSD 213	Phi	MOS-N-FET-e*	=BSD 212: integr. Gateschutz-Di/Gate Protection	5k	TO-72			-
BSD 214	Phi	MOS-N-FET-e	S, Chopper, sym, 40/20/40V, 50mA, on<70Ω, 1/5ns	5k	TO-72			SD 210
BSD 215	Phi	MOS-N-FET-e*	=BSD 214: integr. Gateschutz-Di/Gate Protection	5k	TO-72			SD 211
BSD 254	Phi	MOS-N-FET-d	VFET,250/20V, 0,2/1,2A, 0,85W,<12Ω(0,25A), 10/30ns	7c	TO-92			-
BSD 254 A		MOS-N-FET-d	=BSD 254:	7a	TO-92			-
BSD 254 AR		MOS-N-FET-d	=BSD 254:	7e	TO-92			-
BSJ								
BSJ 30	Riz	Si-N	S, -/30V, 0,8W, 250MHz	2a	TO-5			BC 140…141, 2N1613, 2N1711, ++
BSJ 32	Riz	Si-N	S, -/40V, 0,8W, 300MHz	2a	TO-5			BC 140…141, 2N1613, 2N1711, ++
BSJ 36	Riz	Si-P	S, 40/40V, 0,5A, 0,36W, 200MHz, <40/-ns	2a	TO-18			BSW 24, BSX 36, 2N2906…2907
BSJ 61	Riz	Si-N	S, 25/15V, 0,36W, >400MHz, <40/-ns, hFE>20	2a	TO-18			BSW 41, BSY 62…63, 2N706A, 2N2221…22++
BSJ 62	Riz	Si-N	=BSJ 61: hFE=20…60	2a	TO-18			BSW 41, BSY 62…63, 2N706A, 2N2221…22++
BSJ 63	Riz	Si-N	S, 40/15V, 0,2A, 0,36W, 400MHz, <40/-ns	2a	TO-18			BSW 41, BSY 63, 2N708, 2N2221…22, ++
BSJ 65	Riz	Si-N	S, 25/15V, 0,36W, >400MHz, <40/-ns	2a	TO-18			BSW 41, BSY 62…63, 2N706A, 2N2221…22++
BSJ 66	Riz	Si-N	S, 40V, 0,2A, 0,36W, >350MHz, <35/-ns	2a	TO-18			BSW 41, BSY 63, 2N708, 2N2221…22, ++
BSJ 67	Riz	Si-N	S, 40/15V, 0,5A, 0,36W, 500MHz, <25/-ns	2a	TO-18			BSS 10, BSX 26, BSX 39, 2N3261
BSJ 68	Riz	Si-N	S, 40/15V, 0,5A, 0,36W, 500MHz, <9/-ns	2a	TO-18			BSS 10, BSX 26, BSX 39, 2N3261
BSJ 79	Riz	Si-N	Nixie, Vid, -/120V, 0,03A, 0,3W, 120MHz	2a	TO-18			BF 297…299, BF 422, BF 483, ++
BSJ 108	Phi	N-FET	Sym, S, 25V, Idss>80mA, Up=3…10V, on<8Ω, 10/6ns	2b	TO-18			J 108, 2N5433
BSJ 109	Phi	N-FET	=BSJ 108: Idss>40mA, Up=2…6V, <12Ω	2b	TO-18			J 109
BSJ 110	Phi	N-FET	=BSJ 108: Idss>10mA, Up=0,5…4V, <18Ω	2b	TO-18			BFS 76, BFS 79, J 110
BSJ 111	Phi	N-FET	Chopper, sym, 40/40V, Idss>20mA, Up=3…10V, <30Ω	7d	TO-92			-
BSJ 112	Phi	N-FET	=BSJ 111: Idss>5mA, Up=1…5V, on<50Ω	7d	TO-92			-
BSJ 113	Phi	N-FET	=BSJ 111: Idss>2mA, Up=0,5…3V, on<100Ω	7d	TO-92			-
BSJ 174	Phi	P-FET	S, sym, 30/30V, Idss=20…135mA, Up=5…10V, 7/15ns	7a	TO-92			-
BSJ 175	Phi	P-FET	S, sym, 30/30V, Idss=7…70mA, Up=3…6V, 15/30ns	7a	TO-92			-
BSJ 176	Phi	P-FET	S, sym, 30/30V, Idss=2…35mA, Up=1…4V, 35/35ns	7a	TO-92			-
BSJ 177	Phi	P-FET	S, sym, 30/30V, Idss=1,5…20mA, Up<2,25V, 45/45ns	7a	TO-92			-
BSN								
BSN 10	Phi	MOS-N-FET-e	VFET, 50/20V, 0,175/0,3A, 0,83W, <15Ω(0,1A), 2/5ns	7c	TO-92			BS 170, BSS 98, BST 72
BSN 10 A		MOS-N-FET-e	=BSN 10:	7a	TO-92			BS 170, BSS 98, BST 72
BSN 12	Phi	MOS-N-FET-e	VFET, 50/20V, 0,150/0,3A, 0,83W,<20Ω(0,1A), <4/8ns	7c	TO-92			BS 170, BSS 98, BST 72
BSN 12 A		MOS-N-FET-e	=BSN 12:	7a	TO-92			BS 170, BSS 98, BST 72
BSN 20	Phi	MOS-N-FET-e	=BSN 10: SMD, 0,1/0,3A	35a	SOT-23			BSS 123, BSS 138, BSS 145, 2SK1590
BSN 22	Phi	MOS-N-FET-e	=BSN 12: SMD, 0,1/0,3A	35a	SOT-23			BSS 123, BSS 138, BSS 145, 2SK1590
BSN 65 F	Phi	MOS-N-FET-e	V-MOS, 30/30V, 1,5A, 10W, on<3Ω, 10/10ns	13n	TO-202			-
BSN 204	Phi	MOS-N-FET-e	VFET, 200/20V, 0,25/1A, 1W, <8Ω(0,1A), 5/20ns	7c	TO-92			BSS 88…89, BSN 254, BST 74
BSN 204 A		MOS-N-FET-e	=BSN 204:	7a	TO-92			BSS 88…89, BSN 254, BST 74
BSN 205	Phi	MOS-N-FET-e	VFET, 200/20V, 0,3/1,2A, 1W, <6Ω(0,4A), 5/15ns	7c	TO-92			BSS 88…89, BSN 254, BST 74
BSN 254	Phi	MOS-N-FET-e	VFET, 250/20V, 0,3/1,2A, 1W, <7Ω(0,3A), 5/20ns	7c	TO-92			BSN 274
BSN 254 A		MOS-N-FET-e	=BSN 254:	7a	TO-92			BSN 274

Original	Fabric.	Constr.	Info	(Compl.	Fig.	JAEGER	Fig.	International
BSN 274	Phi	MOS-N-FET-e	VFET, 270/20V, 0.25/1A, 1W, <8Ω(0,25A), 5/20ns		7c	TO-92		BSN 304
BSN 274 A		MOS-N-FET-e	=BSN 274:		7a	TO-92		BSN 304
BSN 304	Phi	MOS-N-FET-e	VFET, 300/20V, 0.25/1A, 1W, <8Ω(0,25A), 2,5/17ns		7c	TO-92		-
BSN 304 A		MOS-N-FET-e	=BSN 304:		7a	TO-92		-
BSP								
BSP 15	Phi	Si-P	=BST 15: 1,5W	(BSP20	≈39°j	SOT-223		-
BSP 16	Phi	Si-P	=BST 16: 1,5W	(BSP19	≈39°j	SOT-223		-
BSP 17	Sie	MOS-N-FET-e	VFET, 50/20V, 2,9/11,6A, <0,1Ω(2,9A), 60/95ns		≈39°c	SOT-223		-
BSP 19	Phi	Si-N	=BST 39: 1,5W	(BSP16	≈39°j	SOT-223		-
BSP 20	Phi	Si-N	=BST 40: 1,5W	(BSP15	≈39°j	SOT-223		-
BSP 30	Phi	Si-P	=BSR 30: 1,5W	(BSP40	≈39°j	SOT-223		-
BSP 31	Phi	Si-P	=BSR 31: 1,5W	(BSP31	≈39°j	SOT-223		-
BSP 32	Phi	Si-P	=BSR 32: 1,5W	(BSP42	≈39°j	SOT-223		-
BSP 33	Phi	Si-P	=BSR 33: 1,5W	(BSP43	≈39°j	SOT-223		-
BSP 40	Phi	Si-N	=BSR 40: 1,5W	(BSP30	≈39°j	SOT-223		-
BSP 41	Phi	Si-N	=BSR 41: 1,5W	(BSP31	≈39°j	SOT-223		-
BSP 42	Phi	Si-N	=BSR 42: 1,5W	(BSP32	≈39°j	SOT-223		-
BSP 43	Phi	Si-N	=BSR 43: 1,5W	(BSP33	≈39°j	SOT-223		-
BSP 50	Phi,Sie	Si-N-Darl+Di	=BST 50: 1,5W	(BSP60	≈39°j	SOT-223		-
BSP 51	Phi,Sie	Si-N-Darl+Di	=BST 51: 1,5W	(BSP61	≈39°j	SOT-223		-
BSP 52	Phi,Sie	Si-N-Darl+Di	=BST 52: 1,5W	(BSP62	≈39°j	SOT-223		-
BSP 60	Phi,Sie	Si-P-Darl+Di	=BST 60: 1,5W	(BSP50	≈39°j	SOT-223		-
BSP 61	Phi,Sie	Si-P-Darl+Di	=BST 61: 1,5W	(BSP51	≈39°j	SOT-223		-
BSP 62	Phi,Sie	Si-P-Darl+Di	=BST 62: 1,5W	(BSP52	≈39°j	SOT-223		-
BSP 88	Sie	MOS-N-FET-e	=BSS 88: 0,29/1,16A, on<8Ω(0,29A)		≈39°c	SOT-223		BSP 126
BSP 89	Phi,Sie	MOS-N-FET-e	=BSS 89: 0,34/1,36A, on<6Ω(0,34A)		≈39°c	SOT-223		BSP 121
BSP 92	Phi,Sie	MOS-P-FET-e	=BSS 92: 0,18/0,72A, on<20Ω(0,18A)		≈39°c	SOT-223		BSP 225
BSP 103	Phi	MOS-N-FET-e	VFET, LogL, 35/30V, 0,7/1A, 1,5W, <1,8Ω(1A), <10ns		≈39°c	SOT-223		-
BSP 105	Phi	MOS-N-FET-e	VFET, LogL, 60/30V, 0,5/1A, 1,5W, <3Ω(1A), <10/-ns		≈39°c	SOT-223		-
BSP 106	Phi	MOS-N-FET-e	VFET, LogL, 60/20V, 0,425/0,85A, 1,5W, <4Ω(0,2A)		≈39°c	SOT-223		-
BSP 107	Phi	MOS-N-FET-e	VFET, LogL, 200/20V, 0,2/0,35A, 1,5W, 14Ω(0,15A)		≈39°c	SOT-223		-
BSP 108	Phi	MOS-N-FET-e	VFET, 80/20V, 0,5/1A, 1,5W, <3Ω(0,5A), 2/10ns		≈39°c	SOT-223		-
BSP 109	Phi	MOS-N-FET-e	VFET, LogL, 90/30V, 0,45/1A, 1,5W, <4Ω(1A), <10ns		≈39°c	SOT-223		-
BSP 110	Phi	MOS-N-FET-e	VFET, LogL, 80/20V, 0,325/0,65A, 1,5W, <10Ω(0,15A)		≈39°c	SOT-223		-
BSP 120	Phi	MOS-N-FET-e	VFET, LogL, 200/20V, 0,25/0,8A, 1,5W, <12Ω(0,25A)		≈39°c	SOT-223		BSP 128
BSP 121	Phi	MOS-N-FET-e	VFET, LogL, 200/20V, 0,35/1,2A, 1,5W, <6Ω(0,4A)		≈39°c	SOT-223		BSP 128
BSP 122	Phi	MOS-N-FET-e	VFET,LogL, 200/20V, 0,55/3A, <2,5Ω(0,75A),<35/50ns		≈39°c	SOT-223		BSP 297
BSP 124	Phi	MOS-N-FET-d	VFET, 250/20V, 0,25/1,2A, <12Ω(0,25A), <10/30ns		≈39°c	SOT-223		-
BSP 125	Sie	MOS-N-FET-e	=BSS 125: 0,12/0,48A, on<45Ω(0,11A)		≈39°c	SOT-223		-
BSP 126	Phi	MOS-N-FET-e	VFET, LogL, 250/20V, 0,35/1,2A, <7Ω(0,3A), 5/20ns		≈39°c	SOT-223		BSP 121
BSP 127	Phi	MOS-N-FET-e	VFET, LogL, 270/20V, 0,35/1,4A, <8Ω(0,25A), 5/20ns		≈39°c	SOT-223		BSP 130
BSP 128	Phi	MOS-N-FET-e	VFET, LogL, 200/20V, 0,35/1,4A, <8Ω(0,1A), 5/20ns		≈39°c	SOT-223		BSP 130
BSP 129	Sie	MOS-N-FET-d	=BSS 129: 0,2/0,6A		≈39°c	SOT-223		BSP 124
BSP 130	Phi	MOS-N-FET-e	VFET,LogL, 300/20V, 0,3/1,4A, <8Ω(0,25A), 2,5/17ns		≈39°c	SOT-223		-
BSP 135	Sie	MOS-N-FET-d	=BSS 135: 0,1/0,3A		≈39°c	SOT-223		-
BSP 149	Sie	MOS-N-FET-d	=BSS 149: 0,48/1,44A, on<3,5Ω(30mA)		≈39°c	SOT-223		-
BSP 152	Phi	MOS-N-FET-e	VFET, 200/40V, 0,55/3A, <2,5Ω(0,75A), <15/30ns		≈39°c	SOT-223		(BSP 122)
BSP 171	Sie	MOS-P-FET-e	VFET, 60/20V, 1,7/6,4A, on<0,35Ω(1,6A), 86/510ns		≈39°c	SOT-223		-
BSP 204	Phi	MOS-P-FET-e	VFET, 200/20V, 0,25/0,6A, 1W, <15Ω(0,2A), 5/20ns		7c	TO-92		BS 192, BS 208, BSS 92, BSS 192
BSP 204A	Phi	MOS-P-FET-e	=BSP 204:		7a	TO-92		BS 192, BS 208, BSS 92, BSS 192
BSP 205	Phi	MOS-P-FET-e	VFET, 60/20V, 0,275/0,55A, 1,5W, <10Ω(0,2A),3/10ns		≈39°c	SOT-223		-
BSP 206	Phi	MOS-P-FET-e	VFET, 60/20V, 0,35/0,7A, 1,5W, <6Ω(0,2A), 4/15ns		≈39°c	SOT-223		-
BSP 220	Phi	MOS-P-FET-e	VFET, LogL, 200/20V, 0,225/0,6A, 1,5W, <12Ω(0,2A)		≈39°c	SOT-223		BSP 317
BSP 225	Phi	MOS-P-FET-e	VFET, LogL, 250/20V, 0,225/0,6A, 1,5W, <15Ω(0,2A)		≈39°c	SOT-223		-
BSP 254	Phi	MOS-P-FET-e	VFET, LogL, 250/20V, 0,2/0,6A, <15Ω(0,2A), 5/20ns		7c	TO-92		BSS 92
BSP 254 A		MOS-P-FET-e	=BSP 254:		7a	TO-92		BSS 92
BSP 295	Sie	MOS-N-FET-e	=BSS 295: 1,7/6,8A, on<0,3Ω(1,7A)		≈39°c	SOT-223		-
BSP 296	Sie	MOS-N-FET-e	=BSS 296: 1/4A, on<0,8Ω(1A)		≈39°c	SOT-223		-
BSP 297	Sie	MOS-N-FET-e	=BSS 297: 0,65/2,6A, on<2Ω(0,65A)		≈39°c	SOT-223		BSP 122
BSP 298	Sie	MOS-N-FET-e	VFET, 400/20V, 0,5/2A, on<3Ω(0,5A), 35/50ns		≈39°c	SOT-223		-
BSP 299	Sie	MOS-N-FET-e	VFET, 500/20V, 0,4/1,6A, on<4Ω(0,4A), 23/85ns		≈39°c	SOT-223		-
BSP 315	Sie	MOS-P-FET-e	V-MOS,LogL,50/20V, 1,1/4,4A, <0,8Ω(1,1A), 43/220ns		≈39°c	SOT-223		BSP 171
BSP 316	Sie	MOS-P-FET-e	VFET, LogL, 100/20V, 0,65/2,6A, <2,2Ω(0,65A)		≈39°c	SOT-223		-
BSP 317	Sie	MOS-P-FET-e	VFET,LogL,200/20V, 0,37/1,5A, <6Ω(0,37A), 38/170ns		≈39°	SOT-223		-
BSP 318	Sie	MOS-N-FET-e	VFET, 60/20V, 2,6/10,4A, on<0,15Ω(2,6A), 42/160ns		≈39°	SOT-223		-
BSP 324	Sie	MOS-N-FET-e	VFET, 400/20V, 0,17/0,68A, on<25Ω(0,17A), 15/23ns		≈39°	SOT-223		BSP 299
BSP 350	Sie	IC	High-side Switch		≈39°	SOT-223		-
BSR								
BSR 12	Phi	Si-P	SMD, S, 15/15V, 0,1/0,2A, >1,5GHz, <20/30ns		35a	SOT-23		2SA1764
BSR 12 R		Si-P	=BSR 12:		35d	SOT-23		-
BSR 13	Phi,Nsc,Tho	Si-N	SMD, HF,S, 60/30V, 0,8A, >250MHz, <35/285ns		35a	SOT-23		BSR 14, BSS 79, BSS 81
BSR 13 R		Si-N	=BSR 13:		35d	SOT-23		BSR 14R
BSR 14	Phi,Nsc,Tho	Si-N	SMD, HF,S, 75/40V, 0,8A, >300MHz, <35/285ns		35a	SOT-23		BSS 79, BSS 81
BSR 14 R		Si-N	=BSR 14:		35d	SOT-23		-
BSR 15	Phi,Nsc,Tho	Si-P	SMD, HF,S, 60/40V, 0,6A, >200MHz, <50/110ns		35a	SOT-23		BSS 80, BSS 82
BSR 15 R		Si-P	=BSR 15:		35d	SOT-23		-
BSR 16	Phi,Nsc,Tho	Si-P	=BSR 15: 60/60V		35a	SOT-23		BSS 80, BSS 82
BSR 16 R		Si-P	=BSR 16:		35d	SOT-23		-
BSR 17(A)	Phi,Nsc	Si-N	SMD, HF,S, 60/40V, 0,2A, >250MHz, <70/250ns		35a	SOT-23		BSR 13…14, BSS 79, BSS 81
BSR 17(A)R		Si-N	=BSR 17:		35d	SOT-23		BSR 13R…14R
BSR 18(A)	Phi,Nsc	Si-P	SMD, HF,S, 40/40V, 0,2A, >200MHz, <70/300ns		35a	SOT-23		BSR 15…16, BSS 80, BSS 82
BSR 18(A)R		Si-P	=BSR 18:		35d	SOT-23		BSR 15R…16R
BSR 19	Phi,Nsc	Si-N	SMD, HF,S, 160/140V, 0,6A, >100MHz, F<10dB(1kHz)		35a	SOT-23		-
BSR 19 A		Si-N	=BSR 19: 180/160V		35a	SOT-23		-
BSR 20	Phi,Nsc	Si-P	SMD, HF,S, 130/120V, 0,6A, >100MHz, F<8dB(1kHz)		35a	SOT-23		-
BSR 20 A		Si-P	=BSR 20: 160/150V		35a	SOT-23		-
BSR 30	Phi	Si-P	SMD, LF,S, 70/60V, 1A, >100MHz, <500/650ns hFE=40…120	(BSR40	39b	SOT-89		-
BSR 31	Phi	Si-P	=BSR 30: hFE=100…300	(BSR41	39b	SOT-89		-
BSR 32	Phi	Si-P	=BSR 30: 90/80V	(BSR42	39b	SOT-89		-
BSR 33	Phi	Si-P	=BSR 30: 90/80V, hFE=100…300	(BSR43	39b	SOT-89		-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BSR 40	Phi	Si-N	SMD, LF,S, 70/60V, 1A, >100MHz, <250/1000ns hFE=40…120	{BSR30	39b	SOT-89			-
BSR 41	Phi	Si-N	=BSR 40: hFE=100…300	{BSR31	39b	SOT-89			-
BSR 42	Phi	Si-N	=BSR 40: 90/80V	{BSR32	39b	SOT-89			-
BSR 43	Phi	Si-N	=BSR 40: 90/80V, hFE=100…300	{BSR33	39b	SOT-89			-
BSR 50	Phi	Si-N-Darl+Di	S, 60/45V, 1/2A, 0,8W, 350MHz, hFE>2000	{BSR60	7c	TO-92	BC 879	7c	BC 618, BC 875, BC 877, BC 879, 2SD893A+
BSR 51	Phi	Si-N-Darl+Di	=BSR 50: 80/60V	{BSR61	7c	TO-92	BC 879	7c	BC 618, BC 877, BC 879, 2SD1153, 2SD2116
BSR 52	Phi	Si-N-Darl+Di	=BSR 50: 100/80V	{BSR62	7c	TO-92	BC 879	7c	BC 879, 2SD1660, 2SD1978, 2SD1981
BSR 55	Sie	Si-N-Darl	100/100V, 1A, >100MHz, >100MHz, hFE>1500		2a	TO-39			2SC1879, 2SD406, 2SD688
BSR 56	Nsc,Phi,Tho	N-FET	SMD, S, 40V, Idss>50mA, Up=4…10V, <25Ω, <9/25ns		35b	SOT-23			-
BSR 57	Nsc,Phi,Tho	N-FET	=BSR 56: Idss=20…200mA, Up=2…6V, <40Ω, <10/50ns		35b	SOT-23			-
BSR 58	Nsc,Phi,Tho	N-FET	=BSR 56: Idss=8…80mA, Up=0.8…4V, <60Ω, <20/100ns		35b	SOT-23			-
BSR 59	Tix	Si-N-Darl	S, 15/15V, 5A, >100MHz, hFE>1500, <350/-ns		2a	TO-39			2N5425…5426
BSR 60	Phi	Si-P-Darl+Di	S, 60/45V, 1/2A, 0,8W, 350MHz, hFE>2000	{BSR50	7c	TO-92	BC 880	7c	BC 876, BC 878, BC 880, 2SB865, 2SB1406+
BSR 61	Phi	Si-P-Darl+Di	=BSR 60: 80/60V	{BSR51	7c	TO-92	BC 880	7c	BC 878, BC 880, 2SB865, 2SB1129, 2SB1406
BSR 62	Phi	Si-P-Darl+Di	=BSR 60: 100/80V		7c	TO-92	BC 880	7c	BC 880, 2SB1256, 2SB1387
BSR 111	Phi	N-FET	=BSJ 111: SMD		35b	SOT-23			PMBFJ 111
BSR 112	Phi	N-FET	=BSJ 112: SMD		35b	SOT-23			PMBFJ 112
BSR 113	Phi	N-FET	=BSJ 113: SMD		35b	SOT-23			PMBFJ 113
BSR 174	Phi	P-FET	=BSJ 174: SMD		35b	SOT-23			PMBFJ 174
BSR 175	Phi	P-FET	=BSJ 175: SMD		35b	SOT-23			PMBFJ 175
BSR 176	Phi	P-FET	=BSJ 176: SMD		35b	SOT-23			PMBFJ 176
BSR 177	Phi	P-FET	=BSJ 177: SMD		35b	SOT-23			PMBFJ 177
BSS									
BSS 10	Sgs	Si-N	SS, 40/15V, 0,5A, 0,3W, 830MHz, <13/16ns		2a	TO-18			BSX 26, BSX 39, =2N3261
BSS 11	Sgs	Si-N	SS, 40/15V, 0,2A, 0,36W, >500MHz, <12/18ns		2a	TO-18			BSX 19…20, 2N2368, 2N2369(A), 2SC3732++
BSS 12	Sgs	Si-N	SS, 30/12V, 0,2A, 0,36W, >400MHz, <15/20ns		2a	TO-18			BSS 11, BSW 38, 2N2368…69, 2N3011, ++
BSS 13	Sgs	Si-N	S,Drv, 60/35V, 1A, 1W, 350MHz, 18/35ns		2a	TO-39			BSS 27, BSV 77, 2N5189, 2SC1386, ++
BSS 14	Sgs	Si-N	S,Drv, 75/50V, 2/3A, 1W, 350MHz, 18/35ns		2a	TO-39			2N3506…3507, 2N5262
BSS 15	Sgs	Si-N	HF,S, 100/75V, 2A, 1W, >50MHz, <80/800ns	{BSS17	2a	TO-39			=2N5320, 2SD854
BSS 16	Sgs	Si-N	=BSS 15: 75/50V, (=2N5321)	{BSS18	2a	TO-39			2N5320…5321, 2SD854
BSS 17	Sgs	Si-P	HF,S, 100/75V, 2A, 1W, >50MHz, <100/1000ns	{BSS15	2a	TO-39			=2N5322
BSS 18	Sgs	Si-P	=BSS 17: 75/50V, (=2N5323)	{BSS16	2a	TO-39			BSV 82, 2N5322…5323
BSS 19	Tix	Si-N	Nixie Drv, 120/120V, 0,05A, 0,225W, >50MHz		9c				BF 297…299, BF 422, BSS 38, BSX 21
BSS 20	Tix	Si-N	=BSS 19: 160/160V		9c				BF 297…299, BF 422, 2SC3468, 2SC4218
BSS 21	Tix	Si-N	SS, 30/12V, 0,2A, 0,25W, >400MHz, <15/23ns		7a	SOT-30			BSS 11…12, BSW 38, 2N2368…2369(A), ++
BSS 22	Tix	Si-P	S, 12/12V, 0,2A, 0,25W, >400MHz, <60/75ns		7a	SOT-30			BSV 21, BSW 25, BSW 37, BSX 29, 2N3012++
BSS 23	Aeg,Tix	Si-N	S,Drv, 45/40V, 1A, 0,5W, >200MHz, 25/40ns		2a	TO-18			BSS 26, BSW 26, BSS 40…41, 2N4013…14
BSS 24	Sgs	Si-N	4x NPN, 60/40V, 1A, <35ns		TO-100				-
BSS 25	Sie	Si-P	SMD, S, -/25V, 0,4A, <45/100ns		35a	SOT-23			BSR 15…16, BSS 80, BSS 82
BSS 26	Sgs	Si-N	S,Drv, 60/40V, 1A, 0,36W, 400MHz, 15/40ns		2a	TO-18			BSS 23, BSW 26, BSS 40…41, 2N4013…14
BSS 27	Phi,Tix	Si-N	S,Drv, 70/45V, 1A, 0,8W, 300MHz, <25/40ns		2a	TO-39			BSS 14, BSV 95, 2N3735, 2SC1386
BSS 28	Phi,Tix	Si-N	=BSS 27: 50/30V, <25/45ns		2a	TO-39			BSS 13, BSV 77, BSV 95, 2N3724A, ++
BSS 29	Phi,Tix	Si-N	=BSS 27: 50/30V, <30/50ns		2a	TO-39			BSS 13, BSV 77, BSV 95, 2N3724A, ++
BSS 30	Sgs	Si-N	LF,S,Drv, 100/60V, 1A, 0,8W, 80MHz, (=2N1889)		2a	TO-39			BC 141, BSW 66…68, BSX 46…47, ++
BSS 31	Sgs	Si-N	=BSS 30: 100MHz, (=2N1890)		2a	TO-39			BC 141, BSW 66…68, BSX 46…47, ++
BSS 32	Sgs	Si-N	=BSS 30: 120/80V, 70MHz, (=2N1893)		2a	TO-39			BSS 42…43, BSW 67…68, BSX 47, ++
BSS 33	Tho,Tix	Si-N	S,Vid, 200/200V, 0,4A, >40MHz		2a	TO-39			BFR 57…59, 2SD413, 2SD576, 2SD624
BSS 34	Tix	Si-N	HF,Nixie Drv, 100/80V, 0,2A, 0,625W, >90MHz		7c	TO-92			BFR 86…89, BSS 38, BSX 21, 2SC3245
BSS 35	Tix	Si-N	=BSS 34: 120/100V		7c	TO-92			BFR 86…89, BSS 38, BSX 21, 2SC3245
BSS 36	Tho	Si-N-Darl	0,6W, hFE>400		5	TO-12			-
BSS 37	Phi	Si-P	Nixie Drv, 110/100V, 0,1A, 0,2W, 95MHz		12d	SOT-33			BF 398, BF 435…437, BSS 68, BSV 68
BSS 38	Phi,Sie,Nsc	Si-N	Nixie, 120/100V, 0,1/0,25A, 0,3W, >60MHz	{BSS68	7a	TO-92	BF 420 A	7c	BF 297…299, BFR 86…89, BSX 21, ++
BSS 39	Tix	Si-P	Nixie Drv, 120/120V, 0,1A, 0,225W, hFE>50		9b				BF 398, BF 435…437, BSS 68, BSV 68
BSS 40	Phi,Tix	Si-N	S,Drv, 60/40V, 1A, 0,36W, >200MHz, <35/45ns		2a	TO-18			2N4014
BSS 41	Phi,Tix	Si-N	=BSS 40: 60/30V		2a	TO-18			2N4014
BSS 42	Aeg	Si-N	S, 120/120V, 1,5A, 1W, 100MHz, 40/700ns		2a	TO39			BSV 84, BSW 67…68, BSX 47
BSS 43	Aeg	Si-N	=BSS 42: 150/150V		2a	TO-39			BSW 68, 2SC1860
BSS 44	Aeg,Phi,Sgs	Si-P	S,Drv, 65/60V, 5A, 0,87W, >70MHz, 80/450ns	{BFX34	2a	TO-39			BSS 46, 2N6190…6193
BSS 45	Aeg	Si-N	S,Drv, 85/80V, 5A, 0,87W, <300/1000ns	{BSS46	2a	TO-39			2N5338…5339, 2N4895…4897
BSS 46	Aeg	Si-P	S,Drv,85/80V, 5A, 0,87W, >70MHz, <300/1000ns	{BSS45	2a	TO-39			2N6190…6193
BSS 47	Fer	Si-N	SMD, Nixie Drv, 120V, -/0,1A, hFE>30		35d(2mm)	SOT-323			-
BSS 48	Aeg	Si-N	S,Vid, 300/250V, 1A, 1W, >15MHz, 120/500ns		2a	TO-39			BFQ 38…40, 2N3439…40, 2SC1861…62
BSS 49	Aeg	Si-N	=BSS 48: 400/350V		2a	TO-39			BFQ 40, 2N3440, 2SC1862
BSS 50	Mot,Phi	Si-N-Darl+Di	S, 60/45V, 1/2A, 0,8W, 350MHz, <0,4/2µs, hFE>2000		2a	TO-39	(BD 679)[4]	14h	BCX 21, 2SD406, 2SD688
BSS 51	Mot,Phi	Si-N-Darl+Di	=BSS 50: 80/60V	{BSS61	2a	TO-39	(BD 679)[4]	14h	2SD406, 2SD688
BSS 52	Mot,Phi	Si-N-Darl+Di	=BSS 50: 100/80V	{BSS62	2a	TO-39	(BD 679)[4]	14h	2SD406, 2SD688
BSS 53(A,B)	Itt	Si-P	Vid, -/160V, 0,1A, 0,3W, 70MHz		2a	TO-18			BF 435…437, BF 491…493, BFP 23, BFP 26
BSS 54(A,B)	Itt	Si-P	=BSS 53: -/250V		2a	TO-18			BF 436…437, BF 492…493, BFP 26
BSS 55(A,B)	Itt	Si-P	=BSS 53: -/300V		2a	TO-18			BF 437, BF 493, BFP 26
BSS 56	Fer	Si-N	SMD, S,Drv, 100V, 0,5A, >80MHz		35d(2mm)	SOT-323			(BCX 41R)[6]
BSS 58 A	Aeg	PUT	=BSV 58 A:		7n	TO-92			›BSV 58 A
BSS 58 B	Aeg	PUT	=BSV 58 B:		7n	TO-92			›BSV 58 B
BSS 59	Aeg	Si-N	HF,S, 140/80V, 1A, 0,5W, >100MHz, <200/750ns		2a	TO-18			2SC4616, (BSS 43, BSW 68)[6]
BSS 60	Mot,Phi	Si-P-Darl+Di	S, 60/45V, 1/2A, 0,8W, 350MHz, <0,4/2µs, hFE>2000		2a	TO-39	(BD 680)[4]	14h	2SB678
BSS 61	Mot,Phi	Si-P-Darl+Di	=BSS 60: 80/60V	{BSS51	2a	TO-39	(BD 680)	14h	2SB678
BSS 62	Mot,Phi	Si-P-Darl+Di	=BSS 60: 100/80V		2a	TO-39	(BD 680)	14h	2SB678
BSS 63	Phi,Sie,++	Si-P	SMD, Uni, 110/100V, 0,1A, 85MHz		35a	SOT-23			BCX 42, 2SA1257, 2SA1325, 2SA1330
BSS 63 R		Si-P	=BSS 63:		35d	SOT-23			BCX 42R
BSS 64	Phi,Sie,++	Si-N	SMD, Uni, 120/80V, 0,1/0,25A, 100MHz, <-/1µs		35a	SOT-23			BCX 41, 2SC3143, 2SC3340, 2SC3360
BSS 64 R		Si-N	=BSS 64:		35d	SOT-23			BCX 41R
BSS 65	Fer	Si-P	SMD, S, 12/12V, 0,1A, >400MHz, <60/90ns		35a	SOT-23			BSR 15…16, BSR 18
BSS 65 R		Si-P	=BSS 65:		35d	SOT-23			BSR 15R…16R, BSR 18R
BSS 66	Fer	Si-N	SMD, S, 60/40V, 0,1A, >250MHz, <70/250ns, hFE>50		35a	SOT-23			BSR 17
BSS 66 R		Si-N	=BSS 66:	{BSS69	35d	SOT-23			BSR 17R
BSS 67	Fer	Si-N	=BSS 66: hFE=100…300, >300MHz	{BSS70	35a	SOT-23			BSR 17
BSS 67 R		Si-N	=BSS 67:		35d	SOT-23			BSR 17R
BSS 68	Phi,Sie	Si-P	Nixie, 110/100V, 0,1A, 0,3W, >50MHz	{BSS38	7a	TO-92			BF 398, BF 435…437, BSV 68, 2SA1335,++
BSS 69	Fer	Si-P	SMD, S, 40/40V, 0,1/A, <70/300ns, >200MHz, hFE>50		35a	SOT-23			BSR 15…16, BSR 18
BSS 69 R		Si-P	=BSS 69:	{BSS66	35d	SOT-23			BSR 15R…16R, BSR 18R
BSS 70	Fer	Si-P	=BSS 69: hFE=100…300, >250MHz	{BSS67	35a	SOT-23			BSR 15…16, BSR 18
BSS 70 R		Si-P	=BSS 70:		35d	SOT-23			BSR 15R…16R, BSR 18R

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BSS 71(S)	Mot	Si-N	S,Vid,200/200V, 0,5A, 0,5W, 70MHz, 100/400ns	{BSS74	2a	TO-18			BF 391...93, BF 422A, BFP 22, MPS-A42...43
BSS 72(S)	Mot	Si-N	=BSS 71: 250/250V	{BSS75	2a	TO-18			BF 392...93, BF 422A, BFP 25, MPS-A42
BSS 73(S)	Mot	Si-N	=BSS 71: 300/300V	{BSS76	2a	TO-18			BF 393, BF 420A, BFP 25, MPS-A42
BSS 74(S)	Mot	Si-P	S,Vid,200/200V, 0,5A, 0,5W, 110MHz,100/400ns	{BSS71	2a	TO-18			BF 423A, BF 491...93, BFP 23, MPS-A92...93
BSS 75(S)	Mot	Si-P	=BSS 74: 250/250V	{BSS72	2a	TO-18			BF 423A, BF 492...493, BFP 26, MPS-A92
BSS 76(S)	Mot	Si-P	=BSS 74: 300/300V	{BSS73	2a	TO-18			BF 421A, BF 493, BFP 26, MPS-A92
BSS 77	Mot	Si-N	=BSS 71: 0,8W		2a	TO-39			BSS 48...49, 2N3440, 2SD413, 2SD624
BSS 78	Mot	Si-N	=BSS 72: 0,8W		2a	TO-39			BSS 48...49, 2N3440, 2SD576
BSS 79(B,C)	Mot,Sie,++	Si-N	SMD, LF,S, 75/40V, 0,8/1A, 250MHz, <35/310ns	{BSS80	35a	SOT-23			BSR 14, (BCX 41)
BSS 80(B,C)	Mot,Sie,++	Si-P	SMD, LF,S, 60/40V, 0,8/1A, 250MHz, <50/110ns	{BSS79	35a	SOT-23			(BCX 42)
BSS 81(B,C)	Mot,Sie,++	Si-N	=BSS 79: 75/35V	{BSS82	35a	SOT-23			BSR 14, (BCX 41)
BSS 82(B,C)	Mot,Sie,++	Si-P	=BSS 80: 60/60V	{BSS81	35a	SOT-23			(BCX 42)
BSS 83	Phi,Tho	MOS-N-FET-e*	SMD,HF,S, 15V, 50mA, Up=0,1...2V, <45Ω(0,1A), 1/5ns		44(GDSSub)	SOT-143			-
BSS 84	Phi,Sie	MOS-P-FET-e	SMD,VFET,LogL, 50/20V, 0,13A, <10Ω(0,13A), 43/28ns		35a	SOT-23			2SJ185
BSS 87	Phi,Sie	MOS-N-FET-e	VFET, LogL, 200/14V, 0,29/1,1A, <6Ω(0,4A), 16/55ns		39b	SOT-89			-
BSS 88	Phi,Sie	MOS-N-FET-e	VFET, LogL, 240/10V, 0,25/1A, 1W, on<8Ω(0,25A)		7c	TO-92			BSN 254
BSS 89	Phi,Sie,Six	MOS-N-FET-e	VFET, LogL, 200/14V, 0,29/1,16A, 1W, on<6Ω(0,29A)		7c	TO-92			BSS 91, BSN 254
BSS 91	Phi,Sie	MOS-N-FET-e	VFET, LogL, 200/14V, 0,35/1,4A, 1,5W, on<6Ω(0,35A)		2a	TO-18			BSS 89, BSN 254
BSS 92	Phi,Sie,Six	MOS-P-FET-e	VFET,LogL, 240/20V, 0,15A, 1W,<20Ω(0,15A), 33/67ns		7c	TO-92			BSP 254
BSS 93	Sie	MOS-N-FET-e	=BSS 87: 0,5A, 2,5W		2a	TO-39			BSS 95
BSS 95	Sie	MOS-N-FET-e	VFET, LogL, 240/15V, 0,8/3,2A, 8,3W, on<6Ω(0,5A)		13b	TO-202			-
BSS 97	Sie	MOS-N-FET-e	VFET, 200/14V, 1,5/6A, 10W, on<2Ω(1A), 18/170ns		13b	TO-202			(2SK296, 2SK375)[4]
BSS 98	Sie	MOS-N-FET-e	VFET, LogL, 50/14V, 0,3/1,2A, 0,63W, on<3,5Ω(0,3A)		7a	TO-92			BS 170, 2SK1336
BSS 99	Sgs	Si-N-Darl	80/80V, 4A, >2MHz, hFE>750		2a	TO-39			2SC2208, (BD 679, BD 779, BD 865)[6]
BSS 100	Phi,Sie	MOS-N-FET-e	VFET,100/14V, 0,22/0,9A, 0,63W,<6Ω(0,22A), 10/22ns		7a	TO-92			BS 189, BSS 89, BSS 91, BST 74, BST 76++
BSS 101	Sie	MOS-N-FET-e	VFET,LogL, 240/14V, 0,13/0,52A, 0,63W, <16Ω(0,13A)		7a	TO-92			BSS 89, BSN 254
BSS 110	Sie	MOS-P-FET-e	VFET, LogL, 50/20V, 0,17/0,68A, 0,63W, <10Ω(0,17A)		7a	TO-92			BSS 92, BST 100, 2SJ148
BSS 119	Sie	MOS-N-FET-e	VFET,SMD, 100/14V, 0,17/0,68A, <6Ω(0,17A), 13/29ns		35a	SOT-23			BSS 123
BSS 123	Mot,Phi,Sie	MOS-N-FET-e	SMD, VFET, LogL, 100/14V, 0,17/680A, on<6Ω(0,17A)		35a	SOT-23			BSS 119, 2SK1589, 2SK1591
BSS 124	Sie	MOS-N-FET-e	VFET,400/14V, 0,12/0,48A, 1W, <28Ω(0,12A), 15/33ns		7a	TO-92			-
BSS 125	Sie	MOS-N-FET-e	VFET, 600/14V, 0,1/0,4A, 1W, <45Ω(0,1A), 15/31ns		7c	TO-92			-
BSS 129	Sie,Six	MOS-N-FET-d	VFET, 240/14V, 0,15/0,45A, 1W, <20Ω(14mA), 14/40ns		7c	TO-92			-
BSS 131	Phi,Sie	MOS-N-FET-e	=BSS 101: SMD, 0,1/0,4A, on<16Ω(0,1A)		35a	SOT-23			-
BSS 135	Sie	MOS-N-FET-d	VFET, 600/14V, 0,08/0,24A, 1W, <60Ω(10mA), 14/35ns		7c	TO-92			-
BSS 138	Phi,Sie	MOS-N-FET-e	=BSS 98: SMD, 0,22/0,88A, on<3,5Ω(0,22A)		35a	SOT-23			BSS 145
BSS 139	Sie	MOS-N-FET-d	SMD, VFET, 250/14V, 0,04A, on<100Ω(14mA), 14/25ns		35a	SOT-23			-
BSS 145	Sie	MOS-N-FET-e	SMD,VFET, 65/14V, 0,22/0,88A, <3,5Ω(0,2A), 11/27ns		35a	SOT-23			PMBF 170, BST 82
BSS 149	Sie	MOS-N-FET-d	VFET, 200/14V, 0,35/1A, 1W, <3,5Ω(0,05A), 25/140ns		7c	TO-92			-
BSS 192	Phi,Sie	MOS-P-FET-e	=BSS 92: SMD		39b	SOT-89			2SK848
BSS 229	Sie	MOS-N-FET-d	=BSS 139: 0,07/0,21A		39b	SOT-89			-
BSS 295	Sie	MOS-N-FET-e	VFET, LogL, 50/14V, 1,4/5,6A, 1W, on<0,3Ω(1,4A)		7c	TO-92			2SK975, 2SK2085
BSS 296	Sie	MOS-N-FET-e	VFET, LogL, 100/14V, 0,8/3,2A, 1W, on<0,8Ω(0,8A)		7c	TO-92			2SK423, 2SK941
BSS 297	Sie	MOS-N-FET-e	VFET, LogL, 200/14V, 0,48/1,92A, 1W, <2Ω(0,45A)		7c	TO-92			-
BSS 395	Sie	MOS-N-FET-e	VFET, LogL, 50/14V, 4,4/17A, 10W, on<0,3Ω(2,8A)		13c	TO-202			-
BSS 396	Sie	MOS-N-FET-e	VFET, LogL, 100V, 2A, 10W, <0,8Ω		13c	TO-202			-
BSS 397	Sie	MOS-N-FET-e	VFET, LogL, 200V, 1,5A, 10W, <2Ω		13c	TO-202			-
BST									
BST 10 A....S		Si-Di	Dual				2x 1N4007	31a	
BST 15	Phi	Si-P	SMD, LF,S,Vid, 200/200V, 1A, >15MHz		39b	SOT-89			-
BST 16	Phi	Si-P	=BST 15: 350/300V		39b	SOT-89			-
BST 39	Phi	Si-N	SMD, LF,S/Vid, 450/350V, 1A, >15MHz		39b	SOT-89			-
BST 40	Phi	Si-N	=BST 39: 300/250V		39b	SOT-89			-
BST 50	Phi	Si-N-Darl+Di	SMD, 60/45V, 0,5/1,5A, 350MHz, hFE>2000	{BST60	39b	SOT-89			2SD1470, 2SD1472, 2SD1511
BST 51	Phi	Si-N-Darl	=BST 50: 80/60V	{BST61	39b	SOT-89			2SD1472
BST 52	Phi	Si-N-Darl	=BST 50: 100/80V	{BST62	39b	SOT-89			2SD1472
BST 60	Phi	Si-P-Darl+Di	SMD, 60/45V, 0,5/1,5A, 350MHz, hFE>2000	{BST50	39b	SOT-89			2SB1048, 2SB1126
BST 61	Phi	Si-P-Darl	=BST 60: 80/60V	{BST51	39b	SOT-89			2SB1126
BST 62	Phi	Si-P-Darl	=BST 60: 100/80V	{BST52	39b	SOT-89			-
BST 70	Phi	MOS-N-FET-e	VFET, 80/20V, 0,5/1A, 1W, <3Ω(0,5A), <10/15ns		7c	TO-92			BSS 296, 2SK423, 2SK940...41
BST 70 A		MOS-N-FET-e	=BST 70:		7a	TO-92			›BST 70
BST 72	Phi	MOS-N-FET-e	VFET,80/20V, 0,3/0,6A, 0,83W,<10Ω(0,15A), <10/10ns		7c	TO-92			BSS 88...89, BSS 91, 2SK1337
BST 72 A		MOS-N-FET-e	=BST 72:		7a	TO-92			›BST 72
BST 74	Phi	MOS-N-FET-e	VFET,200/20V, 0,25/0,8A, 1W, <12Ω(0,25A), <10/15ns		7c	TO-92			BSS 88...89, BSS 91, BSN 205
BST 74 A		MOS-N-FET-e	=BST 74:		7a	TO-92			›BST 74
BST 76	Phi	MOS-N-FET-e	VFET, 180/20V, 0,3/0,8A, 1W, <10Ω(15mA), <10/15ns		7c	TO-92			BSS 89, BSS 91, BSS 297
BST 76 A		MOS-N-FET-e	=BST 76:		7a	TO-92			›BST 76
BST 78	Phi	MOS-N-FET-e	VFET,450/20V, 0,75/1,5A, 15W,<14Ω(0,1A), <10/100ns		14b	TO-126			-
BST 80	Phi	MOS-N-FET-e	=BST 70: SMD		39b	SOT-89			2SK601, 2SK1078...1079
BST 82	Phi	MOS-N-FET-e	=BST 72: SMD		35a	SOT-35			-
BST 84	Phi	MOS-N-FET-e	=BST 74: SMD		39b	SOT-89			BSS 87
BST 86	Phi	MOS-N-FET-e	=BST 76: SMD		39b	SOT-89			BSS 87
BST 90	Phi	MOS-N-FET-e	=BST 70: 2,5W		2a	TO-39			-
BST 95	Phi	MOS-N-FET-e	VFET,200/20V, 2A, 10W(Tc=25°), <2Ω(1,5A), <35/50ns		2a	TO-39			-
BST 97	Phi	MOS-N-FET-e	=BST 76: 0,4W		2a	TO-72			-
BST 100	Phi	MOS-P-FET-e	VFET, 60/20V, 0,3/0,8A, 1W, <6Ω(0,2A), 4/20ns		7a	TO-92			2SJ198, 2SJ228, 2SJ231
BST 110	Phi	MOS-P-FET-e	VFET, 60/20V, 0,25/0,5A, 0,83W, <10Ω(0,2A), 4/10ns		7a	TO-92			BSP 204, 2SJ198, 2SJ228, 2SJ231
BST 120	Phi	MOS-P-FET-e	=BST 100: SMD		39b	SOT-89			2SJ199, 2SJ212...213
BST 122	Phi	MOS-P-FET-e	=BST 110: SMD		39b	SOT-89			2SJ199, 2SJ212...213
BST 124	Phi	MOS-N-FET-d	VFET, 250/20V, 0,45/1,2A, <12Ω(0,25A), <10/30ns		14b	TO-126			-
BSt A30 26	Sie	50Hz-Thy	400V, 0,6A(Ta=45°C), 0,95A=, Igt/Ih<10/<40mA		27b		TAG 626-600[4]	17e	CS0,8-04, BStA3026M, CS1,2-04[9]
BSt A30 26 M	Sie	50Hz-Thy	400V, 0,8A(Ta=45°C), Igt/Ih<10/<40mA		27b		TAG 626-600[4]	17e	CS08-04,CS1,2-04,(TAG612-400,TAG606-400)[11]
BSt A30 33		50Hz-Thy	=BStA3026: 500V		27b		TAG 626-600[4]	17e	CS0,8-05, BStA3033M, CS1,2-05[9]
BSt A30 33 M		50Hz-Thy	=BStA3026M: 500V		27b		TAG 626-600[4]	17e	CS08-05,CS1,2-05,(TAG612-600,TAG606-600)[11]
BSt A30 40		50Hz-Thy	=BStA3026: 600V		27b		TAG 626-600[4]	17e	CS0,8-06, BStA3040M, CS1,2-06[9]
BSt A30 40 M		50Hz-Thy	=BStA3026M: 600V		27b		TAG 626-600[4]	17e	CS08-06,CS1,2-06,(TAG612-600,TAG606-600)[11]
BSt A30 46		50Hz-Thy	=BStA3026: 700V		27b				CS0,8-07, BStA3046M, CS1,2-07[9]
BSt A30 46 M		50Hz-Thy	=BStA3026M: 700V		27b				CS08-07,CS1,2-07,(TAG612-700,TAG606-700)[11]
BSt A30 53		50Hz-Thy	=BStA3026: 800V		27b				BStA3053M, (TAG613-800, TAG606-800)[11]
BSt A30 53 M		50Hz-Thy	=BStA3026M: 800V		27b				(TAG612-800, TAG606-800)[11]
BSt B01 06	Sie	50Hz-Thy	100V, 0,8A(Ta=45°C), 1,25A=, Igt/Ih<10/<60mA		27b		TAG 626-600[4]	17e	CS0,8-02, BStA3026M, CS1,2-02[9]
BSt B01 13		50Hz-Thy	=BStB0106: 200V		27b		TAG 626-600[4]	17e	CS0,8-02, CS1,2-02, BStA3026M[9]
BSt B01 26		50Hz-Thy	=BStB0106: 400V		27b		TAG 626-600[4]	17e	CS0,8-04, BStA3026M, CS1,2-04[9]

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BSt B01 33		50Hz-Thy	=BStB0106: 500V		27b		TAG 626-600[4]	17e	CS0,8-05, BStA3033M, CS1,2-05[9]
BSt B01 40		50Hz-Thy	=BStB0106: 600V		27b		TAG 626-600[4]	17e	CS0,8-06, BStA3040M, CS1,2-06[9]
BSt B01 46		50Hz-Thy	=BStB0106: 700V		27b		TAG 626-600[4]	17e	CS0,8-07, BStA3046M, CS1,2-07[9]
BSt B02 06	Sie	50Hz-Thy	100V, 3A(Tc=64°C), 4,7A≈, Igt/Ih<10/<60mA		28a		TAG 626-600[4]	17e	(TAG621-100, TAG626/100, T3,5N400,++)[11]
BSt B02 13		50Hz-Thy	=BStB0206: 200V		28a		TAG 626-600[4]	17e	(TAG621-200, TAG626-200, T3,5N400,++)[11]
BSt B02 26		50Hz-Thy	=BStB0206: 400V		28a		TAG 626-600[4]	17e	(TAG621-400, TAG626-400, T3,5N400,++)[11]
BSt B02 33		50Hz-Thy	=BStB0206: 500V		28a		TAG 626-600[4]	17e	(TAG621-500, TAG626-500, T3,5N600,++)[11]
BSt B02 40		50Hz-Thy	=BStB0206: 600V		28a		TAG 626-600[4]	17e	(TAG621-600, TAG626-600, T3,5N600,++)[11]
BSt B02 46		50Hz-Thy	=BStB0206: 700V		28a				(TAG621-700, TAG626-700, T3,5N800,++)[11]
BSt B04 26	Sie	F-Thy	≈BSt C1226		28a		17088*	17f	›BStC1226
BSt B04 33	Sie	F-Thy	≈BStC1233		28a		17088*	17f	›BStC1233
BSt B04 40	Sie	F-Thy	≈BStC1240		28a		17088*	17f	›BStC1240
BSt B04 46	Sie	F-Thy	≈BStC1246		28a		17088*	17f	›BStC1246
BSt B04 53	Sie	F-Thy	≈BStC1253		28a		17088*	17f	›BStC1253
BSt C01 06	Sie	50Hz-Thy	100V, 5A(Tc=82°C), 8A≈, Igt/Ih<35/<90mA		21b	TO-64			BStC0313, BStD0313, CS5-02, CS8-02[9]
BSt C01 13		50Hz-Thy	=BStC0106: 200V		21b	TO-64			BStC0313, BStD0313, CS5-02, CS8-02[9]
BSt C01 26		50Hz-Thy	=BStC0106: 400V		21b	TO-64			BStC0326, BStD0326, CS5-04, CS8-04[9]
BSt C01 33		50Hz-Thy	=BStC0106: 500V		21b	TO-64			BStC0340, BStD0340, CS5-06, CS8-06[9]
BSt C01 40		50Hz-Thy	=BStC0106: 600V		21b	TO-64			BStC0340, BStD0340, CS5-06, CS8-06[9]
BSt C01 46		50Hz-Thy	=BStC0106: 700V		21b	TO-64			BStC0353, BStD0353, CS5-08, CS8-08[9]
BSt C02 06	Sie	50Hz-Thy	100V, 3,5A(Tc=67°C), 5,5A≈, Igt/Ih<20/<60mA		28a		TAG 626-600[4]	17e	(TAG620-100, BStC1026, TAG625-100,++)[11]
BSt C02 13		50Hz-Thy	=BStC0206: 200V		28a		TAG 626-600[4]	17e	(TAG620-200, BStC1026, TAG625-200,++)[11]
BSt C02 26		50Hz-Thy	=BStC0206: 400V		28a		TAG 626-600[4]	17e	(TAG620-400, BStC1026, TAG625-400,++)[11]
BSt C02 33		50Hz-Thy	=BStC0206: 500V		28a		TAG 626-600[4]	17e	(TAG620-500, BStC1033, TAG625-500,++)[11]
BSt C02 40		50Hz-Thy	=BStC0206: 600V		28a		TAG 626-600[4]	17e	(TAG620-600, BStC1040, TAG625-600,++)[11]
BSt C02 46		50Hz-Thy	=BStC0206: 700V		28a				(TAG620-700, BStC1046, TAG625-700,++)[11]
BSt C03 13	Sie	50Hz-Thy	200V, 11,4A(Tc=85°C), 25A≈, Igt/Ih<40/<30mA		21b				BStD0313, CS5-02, CS8-02[9]
BSt C03 26		50Hz-Thy	=BStC0313: 400V		21b				BStD0326, CS5-04, CS8-04[9]
BSt C03 40		50Hz-Thy	=BStC0313: 600V		21b				BStD0340, CS5-06, CS8-06[9]
BSt C03 53		50Hz-Thy	=BStC0313: 800V		21b				BStD0353, CS5-08, CS8-08[9]
BSt C03 66		50Hz-Thy	=BStC0313: 1000V		21b				BStD0366, CS5-10, CS8-10[9]
BSt C03 80		50Hz-Thy	=BStC0313: 1200V		21b				BStD0380, CS5-12, CS8-12[9]
BSt C05 06	Sie	50Hz-Thy	100V, 5A(Tc=76°C), 8A≈, Igt/Ih<20/<60mA		22a	TO-66	(TAG 626-600)[5]	17e	TAG671-100, TAG676-100[9]
BSt C05 13		50Hz-Thy	=BStC0506: 200V		22a	TO-66	(TAG 626-600)[5]	17e	TAG671-200, TAG676-200[9]
BSt C05 26		50Hz-Thy	=BStC0506: 400V		22a	TO-66	(TAG 626-600)[5]	17e	TAG671-400, TAG676-400[9]
BSt C05 33		50Hz-Thy	=BStC0506: 500V		22a	TO-66	(TAG 626-600)[5]	17e	TAG671-500, TAG676-500[9]
BSt C05 40		50Hz-Thy	=BStC0506: 600V		22a	TO-66	(TAG 626-600)[5]	17e	TAG671-600, TAG676-600[9]
BSt C05 46		50Hz-Thy	=BStC0506: 700V		22a	TO-66			TAG671-700, TAG676-700[9]
BSt C06 06	Sie	F-Thy	100V, 3,2A(Tc=65°C), 5A≈, Igt/Ih<50/<100mA		22a	TO-66	TD 3FP 800H[1]*	17f	S3700B, T3S400, TAG670S-100, TAG675S-100[9]
BSt C06 13		F-Thy	=BStC0606: 200V		22a	TO-66	TD 3FP 800H[1]*	17f	S3700B, T3S400, TAG670S-200, TAG675S-200[9]
BSt C06 26		F-Thy	=BStC0606: 400V		22a	TO-66	TD 3FP 800H[1]*	17f	S3700D, T3S400, TAG670S-400, TAG675S-400[9]
BSt C06 33		F-Thy	=BStC0606: 500V		22a	TO-66	TD 3FP 800H[1]*	17f	S3700M, T3S500, TAG670S-500, TAG675S-500[9]
BSt C06 40		F-Thy	=BStC0606: 600V		22a	TO-66	TD 3FP 800H[1]*	17f	S3700M, T3S600, TAG670S-600, TAG675S-600[9]
BSt C06 43		F-Thy	=BStC0606: 650V		22a	TO-66	TD 3FP 800H[1]*	17f	T3S700, TAG670S-700, TAG675S-700[9]
BSt C06 46		F-Thy	=BStC0606: 700V		22a	TO-66	TD 3FP 800H[1]*	17f	T3S700, TAG670S-700, TAG675S-700[9]
BSt C06 50		F-Thy	=BStC0606: 750V		22a	TO-66	TD 3FP 800H[1]*	17f	TAG670S-800, TAG675S-800[9]
BSt C06 53		F-Thy	=BStC0606: 800V		22a	TO-66	TD 3FP 800H[1]*	17f	TAG670S-800, TAG675S-800[9]
BSt C07 06	Sie	50Hz-Thy	100V, 0,9A(Tc=45°C), 1,45A≈, Igt/Ih<20/<60mA		27b		TAG 626-600[4]	17e	BStC3026, (TAG2,5-100, TAG611-100,++)[11]
BSt C07 13		50Hz-Thy	=BStC0706: 200V		27b		TAG 626-600[4]	17e	BStC3026, (TAG2,5-200, TAG611-200,++)[11]
BSt C07 26		50Hz-Thy	=BStC0706: 400V		27b		TAG 626-600[4]	17e	BStC3026, (TAG2,5-400, TAG611-400,++)[11]
BSt C07 33		50Hz-Thy	=BStC0706: 500V		27b		TAG 626-600[4]	17e	BStC3033, (TAG2,5-500, TAG611-500,++)[11]
BSt C07 40		50Hz-Thy	=BStC0706: 600V		27b		TAG 626-600[4]	17e	BStC3040, (TAG2,5-600, TAG611-600,++)[11]
BSt C07 46		50Hz-Thy	=BStC0706: 700V		27b		TAG 626-600[4]	17e	BStC3046, (TAG2,5-700, TAG611-700,++)[11]
BSt C09 26T92	Sie	F-Thy	Blitzg./Strobo flasher, 400V, Igt<50mA		22a	TO-66			-
BSt C09 30T92		F-Thy	=BStC0926T92: 450V		22a	TO-66			-
BSt C10 26	Sie	50Hz-Thy	400V, 4A(Tc=85°C), 6,2A≈, Igt/Ih<25/<80mA		17e	TO-220	TAG 626-600	17e	TAG625-400, C122D, TIC116D, CS6-04, ++[9]
BSt C10 26 M	Sie	50Hz-Thy	400V, 6A(Tc=85°C), 9,4A≈, Igt/Ih<25/<80mA		17e	TO-220			CS6-04, TAG660-400, S2800D, CS3,5-04, ++[9]
BSt C10 33		50Hz-Thy	=BStC1026: 500V		17e	TO-220	TAG 626-600	17e	TAG625-500, C122E, TIC116E, CS6-06, ++[9]
BSt C10 33 M		50Hz-Thy	=BStC1026M: 500V		17e	TO-220			CS6-06, TAG660-500, S2800E, CS3,5-06, ++[9]
BSt C10 40		50Hz-Thy	=BStC1026: 600V		17e	TO-220	TAG 626-600	17e	TAG625-600, C122M, TIC116M, CS6-06, ++[9]
BSt C10 40 M		50Hz-Thy	=BStC1026M: 600V		17e	TO-220			CS6-06, TAG660-600, S2800M, CS3,5-06, ++[9]
BSt C10 46		50Hz-Thy	=BStC1026: 700V		17e	TO-220			TAG625-700, TIC116S, CS6-07, BStC1046M++[9]
BSt C10 46 M		50Hz-Thy	=BStC1026M: 700V		17e	TO-220			CS6-07, TAG660-700, S2800S, CS3,5-07, ++[9]
BSt C10 53	TO-220	50Hz-Thy	=BStC1026: 800V		17e	TO-220			TAG625-800, TIC116N, CS6-08, BStC1053M++[9]
BSt C10 53 M		50Hz-Thy	=BStC1026M: 800V		17e	TO-220			CS6-08, TAG660-800, S2800N, 2N6399, ++[9]
BSt C12 26	Sie	F-Thy	400V, 2,5A(Tc=80°C), 4A≈, Igt/Ih<50/<100mA		17e	TO-220	17088[15]	17f	S5800D, BT153, CSF11-04, CSF0,7-04 (BStCC0233H, S3900E, 17088)[15]
BSt C12 33		F-Thy	=BStC1226: 500V		17e	TO-220	17088[15]	17f	S5800E, BT153, CSF11-06 (BStCC0233H, S3900E, 17088)[15]
BSt C12 33 S11	Sie	Thy			17e		17127	17e	17126, 17127
BSt C12 40		F-Thy	=BStC1226: 600V		17e	TO-220	17088[15]	17f	S5800M, CSF11-06 (BStCC0240H, S3900MF, 17088)[15]
BSt C12 46		F-Thy	=BStC1226: 700V		17e	TO-220	17088[15]	17f	S5800S, CSF11-08 (BStCC0246H, S3900S, 17088)[15]
BSt C12 50		F-Thy	=BStC1226: 750V		17e	TO-220	17088[15]	17f	S5800N, CSF11-08 (BStCC0253H, S3900SF, 17088)[15]
BSt C12 53		F-Thy	=BStC1226: 800V		17e	TO-220	17088[15]	17f	S5800N, CSF11-08 (BStCC0253H, 17088)[15]
BSt C30 26	Sie	50Hz-Thy	400V, 1A(Ta=45°C), 1,6A≈, Igt/Ih<25/<80mA		27b				(TAG2,5-400, TAG611-400, TAG605-400)[11]
BSt C30 33		50Hz-Thy	=BStC3026: 500V		27b				(TAG2,5-500, TAG611-600, TAG605-600)[11]
BSt C30 40		50Hz-Thy	=BStC3026: 600V		27b				(TAG2,5-600, TAG611-600, TAG605-600)[11]
BSt C30 46		50Hz-Thy	=BStC3026: 700V		27b				(TAG2,5-700, TAG611-700, TAG605-700)[11]
BSt C30 53		50Hz-Thy	=BStC3026: 800V		27b				(TAG2,5-800, TAG611-800, TAG605-800)[11]
BSt C31 26	Sie	50Hz-Thy	400V, 1,5A(Tc=85°C), 2,4A≈, Igt/Ih<25/<80mA		28a		TAG 626-600[4]	17e	(TAG630-400, TAG620-400,++)[11]
BSt C31 26 M	Sie	50Hz-Thy	400V, 2,5A(Tc=85°C), 4A≈, Igt/Ih<25/<80mA		28a		TAG 626-600[4]	17e	(TAG630-400, TAG620-400, BStC1026,++)[11]
BSt C31 33		50Hz-Thy	=BStC3126: 500V		28a		TAG 626-600[4]	17e	BStC3133M, (TAG630-500, TAG620-500,++)[11]
BSt C31 33 M		50Hz-Thy	=BStC3126M: 500V		28a		TAG 626-600[4]	17e	(TAG630-500, TAG620-500, BStC1033,++)[11]
BSt C31 40		50Hz-Thy	=BStC3126: 600V		28a		TAG 626-600[4]	17e	BStC3140M, (TAG630-600, TAG620-600,++)[11]
BSt C31 40 M		50Hz-Thy	=BStC3126M: 600V		28a		TAG 626-600[4]	17e	(TAG630-600, TAG620-600, BStC1040,++)[11]
BSt C31 46		50Hz-Thy	=BStC3126: 700V		28a				BStC3146M, (TAG630-700, TAG620-700,++)[11]
BSt C31 46 M		50Hz-Thy	=BStC3126M: 700V		28a				(TAG630-700, TAG620-700, BStC1046,++)[11]
BSt C31 53		50Hz-Thy	=BStC3126: 800V		28a				BStC3153M, (TAG630-800, TAG620-800,++)[11]
BSt C31 53 M		50Hz-Thy	=BStC3126M: 800V		28a				(TAG630-800, TAG620-800, BStC1053,++)[11]

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BSt CC01 26H	Sie	F-Thy+Di	TV-HA, 400V, 3,2A(Tc=65°), Igt/Ih<50/<100mA, <3µs		22a	TO-66	TD 3FP 800H*	17f	S6087B, TD3F400H, TD4F400H[9]
BSt CC01 26R	Sie	F-Thy+Di	TV-HA, 400V, 3,2A(Tc=65°), Igt/Ih<50/<100mA, <5µs		22a	TO-66	TD 3FP 800R*	17f	S6087A, TD3F400R, TD4F400R[9]
BSt CC01 33H		F-Thy+Di	=BStCC0126H: 500V		22a	TO-66	TD 3FP 800H*	17f	S6087B, TD3F500H, TD4F500H[9]
BSt CC01 33R		F-Thy+Di	=BStCC0126R: 500V		22a	TO-66	TD 3FP 800R*	17f	S6087A, TD3F500R, TD4F500R[9]
BSt CC01 40H		F-Thy+Di	=BStCC0126H: 600V		22a	TO-66	TD 3FP 800H*	17f	S6087B, TD3F600H, TD4F600H[9]
BSt CC01 40R		F-Thy+Di	=BStCC0126R: 600V		22a	TO-66	TD 3FP 800R*	17f	S6087A, TD3F600R, TD4F600R[9]
BSt CC01 46H		F-Thy+Di	=BStCC0126H: 700V		22a	TO-66	TD 3FP 800H*	17f	S6087B, TD3F700H, TD4F700H[9]
BSt CC01 46R		F-Thy+Di	=BStCC0126R: 700V		22a	TO-66	TD 3FP 800R*	17f	S6087A, TD3F700R, TD4F700R[9]
BSt CC01 53H		F-Thy+Di	=BStCC0126H: 800V		22a	TO-66	TD 3FP 800H*	17f	TD3F800H, TD4F800H[9]
BSt CC01 53R		F-Thy+Di	=BStCC0126R: 800V		22a	TO-66	TD 3FP 800R*	17f	TD3F800R, TD4F800R[9]
BSt CC02 20V	Sie	F-Thy+Di			17f		17088*	17f	
BSt CC02 33H	Sie	F-Thy+Di	TV-HA, 500V, 5A(Tc=65°),8A=,Igt/Ih<50/<100mA, <3µs		17f	TO-220	17088*	17f	S3900E, 17088
BSt CC02 33R	Sie	F-Thy+Di	TV-HA, 500V, 5A(Tc=65°),8A=,Igt/Ih<50/<100mA, <5µs		17f	TO-220	17089*	17f	S3901E, 17089
BSt CC02 40H		F-Thy+Di	=BStCC0233H: 600V		17f	TO-220	17088*	17f	S3900MF, 17088
BSt CC02 40R		F-Thy+Di	=BStCC0233R: 600V		17f	TO-220	17089*	17f	S3901MF, 17089
BSt CC02 46H		F-Thy+Di	=BStCC0233H: 700V		17f	TO-220	17088*	17f	S3900S, 17088
BSt CC02 46R		F-Thy+Di	=BStCC0233R: 700V		17f	TO-220	17089*	17f	S3901S, 17089
BSt CC02 53H		F-Thy+Di	=BStCC0233H: 800V		17f	TO-220	17088*	17f	17088
BSt CC02 53R		F-Thy+Di	=BStCC0233R: 800V		17f	TO-220	17089*	17f	17089
BSt CC02 60H		F-Thy+Di	=BStCC0233H: 900V		17f	TO-220	17088*	17f	17088
BSt CC02 60R		F-Thy+Di	=BStCC0233R: 900V		17f	TO-220	17089*	17f	17089
BSt CD06 43H		Thy			22a	TO-66	TD 3FP 800H[1]*	17f	17052
BSt D02 20	Sie	50Hz-Thy	300V, 8,5A(Tc=82°C), 13,5A=, Igt/Ih<50/120mA		21b	TO-64			BTW42/600R
BSt D02 40		50Hz-Thy	=BStD0220: 600V		21b	TO-64			BTW42/600R
BSt D02 60		50Hz-Thy	=BStD0220: 900V		21b	TO-64			BTW42/1000R
BSt D03 13	Sie	50Hz-Thy	200V, 16A(Tc=85°C), 25A=, Igt/Ih<30/<80mA		21b	TO-64			CS8-02[9]
BSt D03 26		50Hz-Thy	=BStD0313: 400V		21b	TO-64			CS8-04[9]
BSt D03 40		50Hz-Thy	=BStD0313: 600V		21b	TO-64			CS8-06[9]
BSt D03 53		50Hz-Thy	=BStD0313: 800V		21b	TO-64			CS8-08[9]
BSt D03 66		50Hz-Thy	=BStD0313: 1000V		21b	TO-64			CS8-10[9]
BSt D03 80		50Hz-Thy	=BStD0313: 1200V		21b	TO-64			CS8-12[9]
BSt D06 43H(1G)	Sie	Thy			22a	TO-66	TD 3FP 800H[1]*	17f	17052
BSt D10 26	Sie	50Hz-Thy	400V, 8A(Tc=85°C), 12,5A=, Igt/Ih<25/<80mA		17e	TO-220			BStD1026M, TIC126D, T7,5N400, TAG680-400[9]
BSt D10 26 M	Sie	50Hz-Thy	400V, 10A(Tc=85°C), 16A=, Igt/Ih<25/<80mA		17e	TO-220			T9,5N400, CS15-04[9]
BSt D10 33		50Hz-Thy	=BStD1026: 500V		17e	TO-220			BStD1033M, TIC126E, T7,5N600, TAG680-500[9]
BSt D10 33 M		50Hz-Thy	=BStD1026M: 500V		17e	TO-220			T9,5N500, CS15-06[9]
BSt D10 40		50Hz-Thy	=BStD1026: 600V		17e	TO-220			BStD1040M, TIC126M, T7,5N600, TAG680-600[9]
BSt D10 40 M		50Hz-Thy	=BStD1026M: 600V		17e	TO-220			T9,5N600, CS15-06[9]
BSt D10 46		50Hz-Thy	=BStD1026: 700V		17e	TO-220			BStD1046M, TIC126S, T7,5N700, TAG680-700[9]
BSt D10 46 M		50Hz-Thy	=BStD1026M: 700V		17e	TO-220			T9,5N700, CS15-07[9]
BSt D10 53		50Hz-Thy	=BStD1026: 800V		17e	TO-220			BStD1052M, TIC126N, T7,5N800, TAG680-800[9]
BSt D10 53 M		50Hz-Thy	=BStD1026M: 800V		17e	TO-220			T9,5N800, CS15-08[9]
BSt D16 66 M	Sie	50Hz-Thy	1000V, 7,5A(Tc=85°C), 12A=, Igt/Ih<10/<50mA		17e	TO-220			-
BSt D16 66 N	Sie	50Hz-Thy	=BStD1666M: Igt/Ih<20/<80mA		17e	TO-220			-
BSt D16 66 P		50Hz-Thy	=BStD1666M: Igt/Ih<50/<150mA		17e	TO-220			-
BSt D16 80 M		50Hz-Thy	=BStD1666M: 1200V		17e	TO-220			-
BSt D16 80 N		50Hz-Thy	=BStD1680M: Igt/Ih<20/<80mA		17e	TO-220			-
BSt D16 80 P		50Hz-Thy	=BStD1680M: Igt/Ih<50/<150mA		17e	TO-220			-
BSt D36 66 M	Sie	50Hz-Thy	1000V, 1A(Ta=45°C), 1,6A=, Igt/Ih<10/<50mA		27b				(BStD1666M)[4]
BSt D36 66 N		50Hz-Thy	=BStD3666M: Igt/Ih<20/<80mA		27b				(BStD1666N)[4]
BSt D36 66 P		50Hz-Thy	=BStD3666M: Igt/Ih<50/<150mA		27b				(BStD1666P)[4]
BSt D36 80 M		50Hz-Thy	=BStD3666M: 1200V		27b				(BStD1680M)[4]
BSt D36 80 N		50Hz-Thy	=BStD3680M: Igt/Ih<20/<80mA		27b				(BStD1680N)[4]
BSt D36 80 P		50Hz-Thy	=BStD3680M: Igt/Ih<50/<150mA		27b				(BStD1680P)[4]
BSt D40 26	Sie	50Hz-Thy	400V, 12A, 19A=, Igt<10mA		29b	TO-203			T10N400H, S6200D, BStD4026M, C232D[9]
BSt D40 26 M	Sie	50Hz-Thy	400V, 15A, 23A=, Igt<10mA		29b	TO-203			C 232D[9]
BSt D40 33		50Hz-Thy	=BStD4026: 500V		29b	TO-203			T10N500H, S6200M, BStD4033M, C232E[9]
BSt D40 33 M		50Hz-Thy	=BStD4026M: 500V		29b	TO-203			C 232M[9]
BSt D40 40		50Hz-Thy	=BStD4026: 600V		29b	TO-203			T10N600H, S6200M, BStD4040M, C232M[9]
BSt D40 40 M		50Hz-Thy	=BStD4026M: 600V		29b	TO-203			C 232M[9]
BSt D40 46		50Hz-Thy	=BStD4026: 700V		29b	TO-203			T10N700H, BStD4046M[9]
BSt D40 46 M		50Hz-Thy	=BStD4026M: 700V		29b	TO-203			-[9]
BSt D40 53		50Hz-Thy	=BStD4026: 800V		29b	TO-203			T10N800H, BStD4053M[9]
BSt D40 53 M		50Hz-Thy	=BStD4026M: 800V		29b	TO-203			-
BSt D41 26		50Hz-Thy	=BStD4026:		21b	≈TO-48			T10N400C, S6210D, BStD4126M, BStE4126,++[9]
BSt D41 26 M		50Hz-Thy	=BStD4026M:		21b	≈TO-48			C230D, BStE4126, BStE4126M[9]
BSt D41 33		50Hz-Thy	=BStD4033:		21b	≈TO-48			T10N500C, S6210M, BStD4133M, BStE4133,++[9]
BSt D41 33 M		50Hz-Thy	=BStD4033M:		21b	≈TO-48			C230E, BStE4133, BStE4133M[9]
BSt D41 40		50Hz-Thy	=BStD4040:		21b	≈TO-48			T10N600C, S6210M, BStD4140M, BStE4140,++[9]
BSt D41 40 M		50Hz-Thy	=BStD4040M:		21b	≈TO-48			C230M, BStE4140, BStE4140M[9]
BSt D41 46		50Hz-Thy	=BStD4046:		21b	≈TO-48			T10N700C, BStD4146M, BStE4146, BStE4146M[9]
BSt D41 46 M		50Hz-Thy	=BStD4046M:		21b	≈TO-48			BStE4146, BStE4146M[9]
BSt D41 53		50Hz-Thy	=BStD4053:		21b	≈TO-48			T10N800C, BStD4153M, BStE4153, BStE4153M[9]
BSt D41 53 M		50Hz-Thy	=BStD4053M:		21b	≈TO-48			BStE4153, BStE4153M[9]
BSt E03 26	Sie	F-Thy	400V, 0,6A(Ta=45°C), Igt/Ih<35/<50mA, <12µs		27b				(S5800D, BT153, TAG650S-400,TAG655S-400)[11]
BSt E03 33		F-Thy	=BStE0326: 500V		27b				(S5800E, BT153, TAG650S-500,TAG655S-500)[11]
BSt E03 40		F-Thy	=BStE0326: 600V		27b				(S5800M, TAG650S-600, TAG655S-600)[11]
BSt E03 46		F-Thy	=BStE0326: 700V		27b				(S5800S, CSF11-08)[11]
BSt E04 26	Sie	F-Thy	400V, 4A(Tc=77°C), 6,3A=, Igt/Ih<50/<100mA, <12µs		22a	TO-66			T3S400, TAG670S-400, TAG675S-400[9]
BSt E04 33		F-Thy	=BStE0426: 500V		22a	TO-66			T3S500, TAG670S-500, TAG675S-500[9]
BSt E04 40		F-Thy	=BStE0426: 600V		22a	TO-66			T3S600, TAG670S-600, TAG675S-600[9]
BSt E04 46		F-Thy	=BStE0426: 700V		22a	TO-66			T3S700, TAG670S-700, TAG675S-700[9]
BSt E40 26	Sie	50Hz-Thy	400V, 18A, 28A=, Igt<50mA		29b	TO-203			BStE4026M[9]
BSt E40 26 M	Sie	50Hz-Thy	400V, 22A, 34A=, Igt<50mA		29b	TO-203			-[9]
BSt E40 33		50Hz-Thy	=BStE4026: 500V		29b	TO-203			BStE4033M[9]
BSt E40 33 M		50Hz-Thy	=BStE4026M: 500V		29b	TO-203			-[9]
BSt E40 40		50Hz-Thy	=BStE4026: 600V		29b	TO-203			BStE4040M[9]
BSt E40 40 M		50Hz-Thy	=BStE4026M: 600V		29b	TO-203			-[9]
BSt E40 46		50Hz-Thy	=BStE4026: 700V		29b	TO-203			BStE4046M[9]
BSt E40 46 M		50Hz-Thy	=BStE4026M: 700V		29b	TO-203			-[9]
BSt E40 53		50Hz-Thy	=BStE4026: 800V		29b	TO-203			BStE4053M[9]
BSt E40 53 M		50Hz-Thy	=BStE4026M: 800V		29b	TO-203			-[9]
BSt E41 26		50Hz-Thy	=BStE4026:		21b	≈TO-48			CS13-04, T15,1N400, TAG16N400, BTW40/400[9]

Original	Fabric.	Constr.	Info	{Compl. Fig.		JAEGER	Fig.	International
BSt E41 26 M		50Hz-Thy	=BStE4026M:	21b	=TO-48			T17N400, T24N400, TAG24N400, CS23-04, ++[9]
BSt E41 33		50Hz-Thy	=BStE4033:	21b	=TO-48			CS13-06, T15,1N600, TAG16N600, BTW40/600[9]
BSt E41 33 M		50Hz-Thy	=BStE4033M:	21b	=TO-48			T17N600, T24N600, TAG24N600, CS23-06, ++[9]
BSt E41 40		50Hz-Thy	=BStE4040:	21b	=TO-48			CS13-06, T15,1N600, TAG16N600, BTW40/600[9]
BSt E41 40 M		50Hz-Thy	=BStE4040M:	21b	=TO-48			T17N600, T24N600, TAG24N600, CS23-06, ++[9]
BSt E41 46		50Hz-Thy	=BStE4046:	21b	=TO-48			CS13-08, T15,1N800, TAG16N800, BTW40/800[9]
BSt E41 46 M		50Hz-Thy	=BStE4046M:	21b	=TO-48			T17N800, T24N800, TAG24N800, CS23-08, ++[9]
BSt E41 53		50Hz-Thy	=BStE4053:	21b	=TO-48			CS13-08, T15,1N800, TAG16N800, BTW40/800[9]
BSt E41 53 M		50Hz-Thy	=BStE4053M:	21b	=TO-48			T17N800, T24N800, TAG24N800, CS23-08, ++[9]
BSt S05 46	Sie	Thy		22a	TO-66	(TAG 626-600)[5]	17e	
BSV								
BSV 10	Sie	Si-P	LF,S, 40/40V, 1A, >50MHz, <500/-ns	2a	TO-39			BC 160…161, BSV 15…17, BSW 40, ++
BSV 11	Sie	Si-P	=BSV 10: 60/60V	2a	TO-39			BC 161, BSV 16…17, BSW 40, ++
BSV 12	Sie	Si-P	=BSV 10: 90/90V	2a	TO-39			BC 161, BCX 60, BSV 17, BSW 40, ++
BSV 15	EUR	Si-P	LF,S, 40/40V, 1A, 5W(Tc=25°), 50MHz, <500/650ns	2a	TO-39			BC 160…161, BCX 60, BSV 82, BSW 40, ++
BSV 16	EUR	Si-P	=BSV 15: 60/60V	2a	TO-39			BC 161, BCX 60, BSV 82, BSW 40, ++
BSV 17	EUR	Si-P	=BSV 15: 90/80V	2a	TO-39			BCX 60, BSS 17, BSV 82, BSW 40, ++
BSV 19	Sie	Si-P	60V, 1A, 1W	2a	TO-39			-
BSV 20(A)	Sgs	MOS-P-FET-e	S, Chopper, 30V, 0,2A, on<250Ω, tr<100ns	5(DGSubS)	TO-72			-
BSV 21	Tix	Si-P	S, 12/12V, 0,2A, 0,36W, >400MHz, <60/90ns	2a	TO-18			BSW 25, BSW 37, BSX 29, 2N2894A, ++
BSV 22	Phi	MOS-N-FET-d	S, Chopper, 30V, ±50mA, on=200Ω, off=100MΩ	5k	TO-72			BFW 96, BSV 81
BSV 23(K,L,M)	Fer	Si-N	S, 25V, 0,2/0,5A, 0,3W, >200MHz	40e	=TO-92			BSS 11…12, BSW 38, BSX 19…20, 2N3011++
BSV 24(K,L,M)	Fer	Si-N	=BSV 23: 20V	40e	=TO-92			BSS 11…12, BSW 38, BSX 19…20, 2N3011++
BSV 25(K,L,M)	Fer	Si-N	SS, 30V, 0,5A, 0,3W, >400MHz, <15/20ns	40e	=TO-92			BSS 11…12, BSW 38, BSX 19…20, 2N3011++
BSV 26(K,L,M)	Fer	Si-N	SS, 40V, 0,5A, 0,3W, >500MHz, <12/18ns	40e	=TO-92			BSS 11, BSX 19…20, 2N2368…69(A), ++
BSV 27(K,L,M)	Fer	Si-N	SS, 30V, 0,5A, 0,3W, >400MHz, <15/20ns	40e	=TO-92			BSS 11…12, BSW 38, BSX 19…20, 2N3011++
BSV 28(K,L,M)	Fer	Si-N	Nixie Drv, 100V, 0,1A, 0,3W	40e	=TO-92			BF 297…299, BFR 86, BSS 38, BSX 21
BSV 29(K,L,M)	Fer	Si-N	=BSV 28: 120V	40e	=TO-92			BF 297…299, BFR 86, BSS 38, BSX 21
BSV 33(K,L,M)	Fer	Si-P	S, 12/12V, 0,2A, 0,3W, >400MHz, <60/60ns	40e	=TO-92			BSV 21, BSW 25, BSW 37, BSX 29, 2N2894++
BSV 34(A)	Sgs	MOS-P-FET-e	Dual, 30V, 0,2A, on<500Ω, Up=6V, tr<100ns	TO-77	D-GsubG DS			-
BSV 35	Fer	Si-N	SMD, SS, 40/15V, 0,5A, >500MHz, <12/18ns	35d(2mm)	SOT-323			-
BSV 35 A		Si-N	=BSV 35: 25V, >300MHz, <40/75ns	35d(2mm)	SOT-323			-
BSV 36	Fer	Si-N	SMD, S, 15/6V, 0,5A, >600MHz, <20/15ns	35d(2mm)	SOT-323			-
BSV 37	Fer	Si-P	SMD, S, 12/12V, 0,5A, >400MHz, <60/90ns	35d(2mm)	SOT-323			-
BSV 38(P)	Tix	N-FET	Min, Chopper, 25V, Idss>50mA, Up=4<10V, ton<9ns					-
BSV 39(P)	Tix	N-FET	Min, Chopper, 25V, Idss>8mA, Up=0,8<6V					-
BSV 40	Itt	Si-N	LF,S, 40/20V, 0,1A, 0.36W, >300MHz, hFE=40…120	2a	TO-18			BSW 41, BSY 63, 2N708, 2N4123, ++
BSV 41	Itt	Si-N	=BSV 40: hFE=100…200	2a	TO-18			BSW 41, BSY 63, 2N708, 2N4123, ++
BSV 42	Itt	Si-P	LF,S, 70/70V, 0,5A, 0,6W, 200MHz	2a	TO-39	BC 161	2a	BC 161, BC 303, BSV 17, BSW 40, ++
BSV 43(A,B)	Itt	Si-P	=BSV 42: 60/60V	2a	TO-39	BC 161	2a	BC 161, BC 303…304, BSV 16…17, ++
BSV 44(A,B)	Itt	Si-P	=BSV 42: 60/40V	2a	TO-39	BC 161	2a	BC 161, BC 303…304, BSV 16…17, ++
BSV 45(A,B)	Itt	Si-P	=BSV 42: 30/30V	2a	TO-39	BC 161	2a	BC 160…161, BC 303…304, BSV 15…17, ++
BSV 46	Itt	Si-P	LF,S, 70/70V, 0,5A, 0,4W, 200MHz	2a	TO-18	BC 640	7c	BC 640, BCY 77, 2N2906A…2907A, ++
BSV 47(A,B)	Itt	Si-P	=BSV 46: 60/60V	2a	TO-18	BC 640	7c	BC 638, BCY 77, 2N2906A…2907A, ++
BSV 48(A,B)	Itt	Si-P	=BSV 46: 60/40V	2a	TO-18	BC 640	7c	BC 638, BCY 77, 2N2906(A)…2907(A), ++
BSV 49(A,B)		Si-P	=BSV 46: 30/30V	2a	TO-18	BC 640	7c	BC 636, BC 327, BCY 78…79, 2N2906…07++
BSV 50 E	Sgs	Si-P	Min, S, 12/12V, 0,1A, 800MHz, <20/-ns	36c				-
BSV 50 F		Si-P	=BSV 50E:	36f				-
BSV 50 G		Si-P	=BSV 50E:	36e				-
BSV 51	Aeg	Si-N	Nixie Drv, 100/80V, 0.2A, 0,25W, >50MHz	9e				BF 297…299, BF 422, BSS 38, BSX 21
BSV 52	Mot,Phi,++	Si-N	SMD, S, 20/12V, 0,1/0,2A, 500MHz, <12/18ns	35a	SOT-23			BSV 65
BSV 52 R		Si-N	=BSV 52:	35d	SOT-23			BSV 65R
BSV 53(P)	Tix	Si-N	Min, S, 40/15V, 0,2A, 400MHz, <12/-ns					-
BSV 54(P)	Tix	Si-N	=BSV 53: 20/12V					-
BSV 55(P)	Tix	Si-P	Min, S, 20/15V, 0,2A, 400MHz, <30/-ns					-
BSV 55A(P)	Tix	Si-P	=BSV 55: 12/12V, <60/-ns					-
BSV 56 A	Aeg	UJT-P	35V, IEM=2A, Ip<6µA, Iv>4mA, η=0.56…0,75 Rbb=4,7…9,1kΩ	5a	TO-72			2N2646, 2N4871
BSV 56 B		UJT-P	=BSV 56 A: η=0,68…0,82	5a	TO-72			-
BSV 56 C		UJT-P	=BSV 56 A: Ip<25µA, η=0,47…0,82, Rbb=4…12kΩ	5a	TO-72			-
BSV 57 A,B,C	Aeg	UJT-P	=BSV 56 A,B,C: Iem=1,5A	7c	TO-92			=BSV 56 A,B,C
BSV 58 A	Aeg	PUT	40V, Ifm=2A, 0,3W, Ip<1µA, Iv>25µA	5u	TO-72			2N6028, 2N6120
BSV 58 B		PUT	=BSV 58 A: Ip<5µA, Iv>70µA	5u	TO-72			2N6027, 2N6116, 2N6119, MPU131, MPU231
BSV 59	Sgs	Si-N	S,Drv, 60/30V, 0,5A, 0,36W, 350MHz, 18/25ns	2a	TO-18			BSX 49, 2N3301…3302, 2N4014
BSV 60	Aeg,Fer	Si-N	S,Drv, 45V, 3A, 0,8W, >50MHz, <500/1000ns	2a	TO-39			BSS 45, BSX 62…64, 2N4237…4239
BSV 61	Phi	Si-N	Min, 20/9V, 0,05A, >500MHz, <12/22ns, hFE=30…300	Chip				-
BSV 62	Phi	Si-N	=BSV 61: 20/12V, >400MHz, hFE=17…50					-
BSV 63	Phi	Si-N	=BSV 61: 20/12V, >400MHz, hFE=30…120					-
BSV 64	Fer,Phi	Si-N	S,Drv, 100/60V, 2/5A, 100MHz, <600/1200ns	2a	TO-39			BCX 40, BSS 15, 2N4239, 2N5320
BSV 65(A,B)	Sie	Si-N	SMD, S, 20/15V, 0,15A, >280MHz, <20/40ns	35a	SOT-23			BSV 52, 2SC1621,2SC3578, 2SC4894
BSV 65R(RA,RB)		Si-N	=BSV 52:	35d	SOT-23			BSV 52R
BSV 68	Phi	Si-P	Nixie Drv, 110/100V, 0,1A, 0,25W, 95MHz	2a	TO-18			BF 398, BF 423, BF 435…437, BSS 68
BSV 69	Aeg	Si-N	S,Drv, 45/40V, 1A, 0,8W, 25/40ns	2a	TO-39			BSS 13, BSS 27…29, BSV 77, 2N5189, ++
BSV 71	Phi	Si-N	Min, S, 15/6V, 0,05A, >600MHz, <20/-ns	Chip				-
BSV 74	Phi	Si-N	Ubr=110V, Ip=1,5A, Ih<400mA, Uh<30V, <4/-ns	2a	TO-18			-
BSV 75	Phi	Si-N	Ubr=60V, Ip=1A, Ih<400mA, UH<30V, <4/-ns	2a	TO-18			-
BSV 76	Phi	Si-N	Ubr=90V, Ip=2A, Ih<400mA, UH<30V, <5/-ns	2a	TO-18			-
BSV 77	Sgs	Si-N	S,Drv, 60/40V, 1A, 0,8W, 400MHz, 15/40ns	2a	TO-39			BSS 13, BSS 27, BSV 95, 2N5189
BSV 78	Phi	N-FET	Chopper, sym, 40V, Idss>50mA, Up=3,75…11V, <25Ω	2b	TO-18			BFS 74, 2N4856
BSV 79	Phi	N-FET	Chopper, sym, 40V, Idss>20mA, Up=2…7V, on<40Ω	2b	TO-18			BFS 75, 2N4857
BSV 80	Phi	N-FET	Chopper, sym, 40V, Idss>10mA, Up=1…5V, on<60Ω	2b	TO-18			BFS 76, 2N4858
BSV 81	Phi	MOS-N-FET-d	Chopper, sym, 30V, 50mA, on<100Ω, off>10GΩ	5m	TO-72			BFW 96, BSV 22
BSV 82	Sgs	Si-P	LF,S, 80/80V, 2/3A, 1W, 60MHz, 50/250ns	2a	TO-39			2N6303
BSV 83	Sgs	Si-P	LF,S, 90/80V, 1A, 0,8W, 100MHz, <35/-ns	2a	TO-39			BSW 40, 2N4036
BSV 84	Sgs	Si-N	LF,S, 120/70V, 2A, 1W, >60MHz, <250/700ns	2a	TO-39			2SC1860,(BSS 42…43, BSW 67…68, BSX 47)[7]
BSV 85	Sgs	Si-N	LF,S, 50/30V, 1A, 0,36W, 250MHz	2a	TO-18			BC 637, BSS 26, BSS 40…41, BSW 26, ++
BSV 86	Phi	Si-N	LF,S, 75/30V, 0,4/1A, >100MHz, 50/210ns, hFE>100	12a	SOT-33			BC 639, BSW 63…64, 2N2221A…2222A, ++
BSV 87	Phi	Si-N	=BSV 86: hFE>40	12a	SOT-33			BC 639, BSW 63…64, 2N2221A…2222A, ++
BSV 88	Phi	Si-N	=BSV 86: 60/25V, hFE>35	12a	SOT-33			BC 637, BSW 61…62, 2N2221…2222, ++
BSV 89	Sgs	Si-N	SS, 25/10V, 0,1A, 0,36W, 600MHz, <12/18ns	2a	TO-18			BSS 11…12, BSX 92…93, 2N2368…69, ++
BSV 90	Sgs	Si-N	=BSV 89: 30/13,5V	2a	TO-18			BSS 11…12, BSX 92…93, 2N2369…69, ++
BSV 91		Si-N	=BSV 89: 40/15V	2a	TO-18			BSS 11…12, BSX 92…93, 2N2368…69

Original	Fabric.	Constr.	Info	(Compl.	Fig.		JAEGER	Fig.	International
BSV 92	Sgs	Si-N	=BSV 89: 40/15V		2a	TO-18			BSS 11…12, BSX 92…93, 2N2368…69, ++
BSV 93	Phi	Si							
BSV 94	Phi	Si							
BSV 95	Sgs	Si-N	S,Drv, 80/50V, 1A, 0,8W, 400MHz, 15/40ns		2a	TO-39			2N3735
BSV 96	Phi	Si-P	LF,S, 30/30V, 0,3/0,8A, 0,22W, 75MHz, hFE=100…250		12a	SOT-33			BC 328, BC 636, BCY 77…79, 2N2906…07++
BSV 97	Phi	Si-P	=BSV 96: hFE=40…120		12a	SOT-33			BC 328, BC 636, BCY 77…79, 2N2906…07++
BSV 98	Phi	Si-P	=BSV 96: hFE>30		12a	SOT-33			BC 328, BC 636, BCY 77…79, 2N2906…07++
BSV 99	Tix	Si-N	SS, 30/12V, 0,2A, 0,25W, >400MHz, <12/-ns		7a	SOT-30			BSS 11…12, BSX 92…93, 2N2368…69, ++
BSVP 20	Ucp	Si-N	Min, 40V, -/0,2A, 150MHz		Chip	TO-122			-
BSVP 30	Ucp	Si-N	Min, 40V, 0,1A, 300MHz		Chip	TO-122			-
BSW									
BSW 10	Aeg	Si-N	LF,S, 90/65V, 0,8A, 0,6W, >200MHz, 100/350ns		2a	TO-39			BSS 42…43, BSW 66…68, BSX 46…47, ++
BSW 11	Aeg	Si-N	Min, S, 25/15V, 0,03A, >400MHz, <25/50ns		36c	(TOM-23)			-
BSW 12	Aeg	Si-N	Min, S, 40/20V, 0,2A, >200MHz, <40/80ns		36c				-
BSW 13	Sie	Si-N	Min, S, 20/15V, 0,05A, >280MHz, <20/40ns		(41c)	(2x1x1.5)			-
BSW 16	Sgs	Si-N	8x NPN, 50/30V, 0,8A, >250Mhz, <50/90ns, (BSX 32)		14-DIP	TO-116			-
BSW 17	Sgs	Si-N	5x NPN, 120/120V, 0,1A, >40MHz, (=BSW 17)		14-DIP	TO-116			-
BSW 18	Sgs	Si-N	=BSW 17: SMD		14-FLP	TO-86			-
BSW 19	Aeg	Si-P	S, 35/30V, 0,1A, 0,3W, >150MHz, <150/800ns		2a	TO-18			BCY 77…79, 2N4034…35, 2N3905…06, ++
BSW 20	Aeg	Si-P	=BSW 19:		7a	TO-92			BCY 77…79, 2N4034…35, 2N3905…06, ++
BSW 21	Mot,Tho,Tix	Si-P	S, 25/25V, 0,2A, 0,3W, 300MHz, 200/-ns, hFE>75		2a	TO-18			BCY 77…79, 2N2906…07, 2N3905…06, ++
BSW 21 A		Si-P	=BSW 21: 50/50V		2a	TO-18			BCY 77, 2N2906…07, 2N3250…51, ++
BSW 22	Mot,Tho,Tix	Si-P	=BSW 21: hFE=180…540		2a	TO-18			BCY 77…79, 2N2906…07, 2N3905…06, ++
BSW 22 A		Si-P	=BSW 22: 50/50V		2a	TO-18			BCY 77, 2N2906…07, 2N3250…51, ++
BSW 23	Mot,Sgs,Tix	Si-P	=2N2904		2a	TO-39			›2N2904
BSW 24	Mot,Sgs,Tix	Si-P	=2N2906		2a	TO-18			›2N2906
BSW 25	Mot,Sgs,Tix	Si-P	=2N2894A		2a	TO-18			›2N2894A
BSW 26	Tix	Si-N	S,Drv, 50/40V, 1A, 0,5W, >200MHz, <40/85ns		2a	TO-18			BSS 26, BSS 40…41
BSW 27	Tix	Si-N	S,Drv, 60/50V, 1A, 0,8W, >200MHz, <40/85ns		2a	TO-39			BSS 14, BSS 27, BSV 95, 2N3735, 2SC1386
BSW 28	Tix	Si-N	=BSW 27: <50/85ns		2a	TO-39			BSS 14, BSS 27, BSV 95, 2N3735, 2SC1386
BSW 29	Tix	Si-N	=BSW 27: 40/30V		2a	TO-39			BSS 14, BSS 27…29, BSV 95, 2N3735, ++
BSW 30	Sgs	MOS-P-FET-e	HF,S, 30V, 0,5A, Up<6V, tr<60ns		5(DGsubS)	TO-72			-
BSW 31	Sgs	MOS-P-FET-e	HF,S, 30V, 0,5A, Up<6V, tr<60ns		5(DGsubS)	TO-72			-
BSW 32	Tix	Si-N	Nixie Drv, 100/80V, 0,03A, 0,25W		7c	TO-92			BF 297…299, BF 422, BSS 38, BSX 21
BSW 33	Phi	Si-N	LF,S, 40/32V, 0,1/0,2A, 300MHz, 0,125W, <200/-ns		12a	SOT-33			BC 167, BC 182, BC 237, BC 547, 2SD767++
BSW 34	Phi	Si-N	=BSW 33: 50/45V		12a	SOT-33			BC 167, BC 182, BC 237, BC 547, 2SD767++
BSW 35	Phi	Si-N	=BSW 33: 60/60V		12a	SOT-33			BC 174, BC 182, BC 190, BC 546, 2SD767++
BSW 36	Tix	Si-P	LF,S, 32/32V, 0,5A, 0,8W, >150MHz, <60/150ns		2a	TO-39			BSW 23, 2N2904(A)…05(A), 2N3072…73
BSW 37	Tix	Si-P	S, 12/12V, 0,2A, 0,36W, >400MHz, <80/90ns		2a	TO-18			BSV 21, BSW 25, BSX 29, 2N2894A, ++
BSW 38	Tix	Si-N	SS, 30/12V, 0,3A, 0,36W, >400MHz, <15/20ns		2a	TO-18			BSS 10, BSX 19…20, BSX 28, 2N3261, ++
BSW 39	Aeg	Si-N	LF,S, 100/80V, 1A, 0,79W, >50MHz, 50/300ns	(BSW40	2a	TO-39			BSS 42, BSW 66…68, BSX 46…47, 2SD854
BSW 40	Aeg	Si-P	LF,S, 100/80V, 1A, 0,79W, >50MHz, 50/300ns	(BSW39	2a	TO-39			BSS 17, 2N5322
BSW 41(A)	Phi	Si-N	S, 40/25V, 0,3/0,5A, 0,32W, >250MHz, <60/60ns		2a	TO-18			BSX 48…49, BSY 63, 2N708, 2N4123, ++
BSW 42(A,B)	Tho	Si-N	S, 25…60V, 0,2A, 0,3W, 300MHz, 70/250ns, hFE>75		8a	TO-106	BC 546	7a	BSV 59, BSX 49, 2N3301…02, 2N3903…04++
			BSW42: 25/25V, A=50/50V, B=60/60V	(BSW44					
BSW 43(A,B)	Tho	Si-N	=BSW 42: hFE=180…540	(BSW45	8a	TO-106	BC 546	7a	BSV 59, BSX 49, 2N3301…02, 2N3903…04++
BSW 44(A,B)	Tho	Si-P	S, 25…60V, 0,2A, 0,3W, >150MHz, 215/105ns, hFE>75		8a	TO-106	BC 556	7a	BCY 77, BSW 24, 2N3250A…3251A, ++
			BSW44: 25/25V, A=50/50V, B=60/60V	(BSW42					
BSW 45(A,B)	Tho	Si-P	=BSW 44: hFE=180…540	(BSW43	8a	TO-106	BC 556	7a	BCY 77, BSW 24, 2N3250A…3251A, ++
BSW 42….45(A)K		Si-N/P	=BSW 42…45(A,B):		7e	TO-92			›BSW 42…45(A,B)
BSW 49	Tho,Tix	Si-N	LF,S, 40/40V, 1A, 0,6W, >200MHz, <-/50ns		2a	TO-39			BSW 27…29, BSX 32, BSX 59…61, 2N3252++
BSW 50	Phi	Si-N	LF,S, 65V, 0,8A, 0,8W, 250MHz		2a	TO-5			BSW 27…28, BSX 32, BSX 59…61, 2N3252++
BSW 51	Mot,Phi,Tix	Si-N	=2N2218		2a	TO-39	›2N2218		›2N2218
BSW 52	Mot,Phi,Tix	Si-N	=2N2219		2a	TO-39	›2N2219		›2N2219
BSW 53	Mot,Phi,Tix	Si-N	=2N2218A		2a	TO-39	›2N2218A		›2N2218A
BSW 54	Mot,Phi,Tix	Si-N	=2N2219A		2a	TO-39	›2N2219A		›2N2219A
BSW 58	Phi	Si-N	SS, 40/15V, 0,5A, 0,125W, >400MHz, <7/18ns		12a	SOT-33			BSS 10, BSX 26, BSX 39, 2N3261
BSW 59	Phi	Si-N	SS, 30/12V, 0,5A, 0,125W, <7/21ns		12a	SOT-33			BSS 10, BSX 26, BSX28, BSX 39, 2N3261
BSW 60	Phi	Si-N	LF,S, 60V, 0,8A, 0,5W, 250MHz		2a	TO-18			BC 337, BC 637, BC 639, 2N2221…22, ++
BSW 61	Mot,Phi,Tix	Si-N	=2N2221		2a	TO-18	›2N2221		›2N2221
BSW 62	Mot,Phi,Tix	Si-N	=2N2222		2a	TO-18	›2N2222		›2N2222
BSW 63	Mot,Phi,Tix	Si-N	=2N2221A		2a	TO-18	›2N2221A		›2N2221A
BSW 64	Mot,Phi,Tix	Si-N	=2N2222A		2a	TO-18	›2N2222A		›2N2222A
BSW 65	Phi	Si-N	S,Drv, 80/80V, 1/2A, 0,7W, 80MHz, 500/1000ns		2a	TO-39			BC 141, BSS 15, BSS 42…43, BSX 45…47++
BSW 66(A)	Phi,Mot	Si-N	=BSW 65: 100/100V		2a	TO-39			BC 141, BSS 15, BSS 42…43, BSX 46…47++
BSW 67(A)	Phi,Mot,Sgs	Si-N	=BSW 65: 120/120V		2a	TO-39			BSS 42…43, BSV 84, BSX 47
BSW 68(A)	Phi,Mot,Sgs	Si-N	=BSW 65: 150/150V		2a	TO-39			BSS 43, 2SC1860
BSW 69	Phi	Si-N	Nixie Drv, 150V, 0,05A, 0,125W, 130MHz		12d	SOT-33			BF 297…299, BF 422, BFT 57…59, ++
BSW 70	Phi	Si-N	Nixie Drv, 100/60V, 0,05A, 0,25W		2a	TO-18			BF 297…299, BF 422, BSS 38, BSX 21, ++
BSW 72	Itt	Si-P	Uni, 40/25V, -/0,5A, 0,4W, >150Mhz, hFE=40…120		2a	TO-18	BC 327	7a	BC 327, BC 636, BCY 79, 2N2906…07, ++
BSW 73	Itt	Si-P	=BSW 72: hFE=100…300		2a	TO-18	BC 327	7a	BC 327, BC 636, BCY 79, 2N2906…07, ++
BSW 74	Itt	Si-P	=BSW 72: 75/40V		2a	TO-18	BC 640	7c	BC 640, 2SA1683, 2SB984, 2SB1116A,++
BSW 75	Itt	Si-P	=BSW 72: 75/40V, hFE=100…300		2a	TO-18	BC 640	7c	BC 640, 2SA1683, 2SB984, 2SB1116A,++
BSW 78	Itt	Si-N	SS,40/15V, 0,2A, 0,2W, >400MHz, <12/15ns, hFE>20		7a	TO-92			BSS 10…11, BSX 19…20, 2N3261, =2N2368
BSW 79	Itt	Si-N	=BSW 78: >500MHz, <12/18ns, hFE=40…120		7a	TO-92			BSS 10…11, BSX 19…20, 2N3261, =2N2369
BSW 80	Itt	Si-N	=BSW 78: >500MHz, <12/18ns, hFE<120		7a	TO-92			BSS 10…11, BSX 19…20, 2N3261, =2N2369A
BSW 81	Itt	Si-P	S, 12/12V, 0,2A, 0,2W, >400MHz, <60/75ns		7a	TO-92			BSX 36, =2N3012
BSW 82	Itt,Tix	Si-N	Uni, 40/25V, -/0,5A, 0,5W, >200MHz, hFE=40…120		2a	TO-18	BC 337	7a	BC 337, BC 635, BCY 59, 2N2221…22, ++
BSW 83	Itt,Tix	Si-N	=BSW 82: hFE=100…300		2a	TO-18	BC 337	7a	BC 337, BC 635, BCY 59, 2N2221…22, ++
BSW 84	Itt,Tix	Si-N	=BSW 82: 75/40V		2a	TO-18	BC 639	7c	BC 639, 2SC4414, 2SD774, 2SD1616A,++
BSW 85	Itt,Tix	Si-N	=BSW 82: 75/40V, hFE=100…300		2a	TO-18	BC 639	7c	BC 639, 2SC4414, 2SB774, 2SD1616A,++
BSW 88(A,B)	Aeg	Si-N	S, 35/30V, 0,1A, 0,3W, >200MHz, <150/800ns		7c	TO-92	BC 546	7a	BSW 41, BSY 63, 2N708, 2N4123, 2SC4414++
BSW 89(A,B)	Aeg	Si-N	=BSW 88:		7a	TO-92	BC 546	7a	BSW 41, BSY 63, 2N708, 2N4123, 2SC4414++
BSW 92	Tho	Si-N	LF,S, 18/18V, 0,2A, 0,3W, >150MHz		8a	TO-106	BC 546	7a	BC 168, BC 183, BC 238, BC 548, 2SD767++
BSW 93	Sgs	Si-P	HF,S, 30/30V, 1A, 1W, 230MHz, 25/65ns		2a	TO-39			2N3467…68, 2SA717
BSW 95(A)	Sgs	MOS-P-FET-e	S, Chopper, 30V, 50mA, Up<6V, on<1,5kΩ, <200/-ns		5(DGsubS)	TO-72			-
BSWP 30	Ucp	MOS-P-FET-e	S, 25V, 0,5A, Up<9V		5n	TO-72			-
BSX									
BSX 12(A)	Fer,Phi,Sgs	Si-N	SS,Drv, 25/12(A=15)V, 1A, 0,6W, 620MHz, 10/15ns		2a	≈TO-39			BSS 27…29, BSV 69, BSV 77, 2N3426
BSX 19	Mot,Phi,++	Si-N	SS,40/15V, -/0,5A, 0,36W, 500MHz, <7/18ns(=2N2368)		2a	TO-18			BSS 10, BSX 26, BSX 39, 2N2368…69(A)
BSX 20	Mot,Phi,++	Si-N	SS,40/15V, -/0,5A, 0,36W, 600MHz, <7/21ns(=2N2369)		2a	TO-18			BSS 10, BSX 26, BSX 39, 2N2368…69(A)

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BSX 21	Phi,Tix	Si-N	Nixie Drv, 120/80V, 0,1/0,25A, 0,3W, 120MHz		2a	TO-18	BF 420 A	7c	BF 297…299, BF 422A, BSS 38, 2SC2145,++
BSX 22	Itt,Tix	Si-N	LF,S, 40/32V, 1,5A, 0,8W, 100MHz		2a	TO-39			BSW 65…68, BSX 45…47, 2N3107…10, ++
BSX 23	Itt,Tix	Si-N	=BSX 22: 90V		2a	TO-39			BSW 66…68, BSX 46…47, 2N3107…08, ++
BSX 24	Itt,Tho,Tix	Si-N	LF,S, 32/32V, 0,1A, 0,3W, 200MHz, 25/400ns		2a	TO-18	BC 546	7a	BC 548, BSW 41, BSY 63, 2N708, 2SC3731++
BSX 25	Aeg,Tix	Si-N	LF,S, 40/25V, 0,3A, 0,36W, >50MHz		2a	TO-18			BC 337, BC 635, BCY 59, 2N2221…22, ++
BSX 26	Sgs,Tix	Si-N	SS, 40/15V, 0,5A, 0,36W, 550MHz, 9/15ns		2a	TO-18			BSS 10, BSX 39, 2N3261, 2SC4648
BSX 27	Sgs,Tix	Si-N	SS, 15/6V, 0,15A, 800MHz, 0,3W, <12/12ns		2a	TO-18			BSS 10…12, BSX 92…93, 2N2368, 2N3011++
BSX 28	Sgs,Tix	Si-N	SS, 30/12V, 0,5A, 0,36W, 650MHz, 9/13ns		2a	TO-18			BSS 10, BSX 26, BSX 39, 2N3261, 2SC4648+
BSX 29	Mot,Sgs,Tix	Si-P	HF,S, 12/12V, 0,2A, 0,36W, 700MHz, 25/35ns		2a	TO-18			BSV 21, BSW 25, BSW 37, BSX 36, 2N2894A
BSX 30	Sgs,Tix	Si-N	S,Drv, 60/30V, 0,8A, 0,8W, 330MHz, 22/22ns		2a	TO-39			BSS 13, BSS 27, BSV 77, 2N5189
BSX 31	Sgs	Si-N	Chopper, 15V		5(E1BCE2)	TO-72			-
BSX 32	Mot,Sgs,++	Si-N	S,Drv, 65/40V, 1A, 0,8W, 450MHz, 35/40ns		2a	TO-39			BSS 13, BSS 27, BSV 77, 2N5189
BSX 33	Sgs,Tix	Si-N	S,Drv, 85/55V, 1A, 0,5W, 90MHz, 120/350ns		2a	TO-18			BC 639, 2N3700…01, 2SC4488, 2SD774,++
BSX 34	Sgs	MOS-P-FET-e	Dual, 30V, 0,2A, Up<6V		TO-77	D-GsubG-DS			-
BSX 35	Sgs,Tix	Si-P	SS, 6/6V, 0,2A, 0,3W, 700MHz, <25/25ns		2a	TO-18			BSX 29, BSX 36, 2N2894A
BSX 36	Mot,Sgs,Tix	Si-P	S, 40/40V, 0,5A, 0,36W, 200MHz, 17/18ns		2a	TO-18	(BC 327)	7a	BSX 29, BSX 35, 2N2894A
BSX 38(A,B)	Aeg	Si-N	LF,S, 35/30V, 0,1/0,2A, 0,3W, >200MHz, <150/800ns		2a	TO-18			BC 548, BCY 59, BSW 41, BSY 63, 2N708,++
BSX 39	Sgs,Tix,++	Si-N	S,Drv, 45/20V, 0,5A, 0,36W, 600MHz, 9/15ns		2a	TO-18			BSS 10, BSX 26, 2N3261
BSX 39	Mot	Si-N	SMD, S,Drv, 45/14V, 0,2A, <12/18ns		35d	SOT-23			-
BSX 40	Itt,Tix	Si-P	LF,S, 30/30V, 0,5A, 0,6W, >100MHz, hFE=40…120		2a	TO-39	BC 161	2a	BC 160…161, BC 303…304, BSV 15…17, ++
BSX 41	Itt,Tix	Si-P	=BSX 40: >150MHz, hFE=100…300		2a	TO-39	BC 161	2a	BC 160…161, BC 303…304, BSV 15…17, ++
BSX 44	Phi,Tix	Si-N	SS, 15/6V, -/0,2A, >600MHz, <20/15ns		2a	TO-18			BSV 89…92, BSX 27, BSX 92…93, 2N2475
BSX 45	EUR	Si-N	LF,S, 80/40V, 1A, 5W(Tc=25°), >50MHz, <200/850ns		2a	TO-39	(BC 141)	2a	BSS 42…43, BSW 65…68, 2N3107…10, ++
BSX 46	EUR	Si-N	=BSX 45: 100/60V		2a	TO-39	(BC 141)	2a	BSS 42…43, BSW 66…68, 2N3107…08, ++
BSX 47	EUR	Si-N	=BSX 45: 120/80V		2a	TO-39	(BC 141)	2a	BSS 42…43, BSW 67…68, 2N3019…20, ++
BSX 48	Mot,Phi,Sie	Si-N	S,Drv, 50/25V, 0,6A, 400MHz, 35/60ns		2a	TO-18			BSV 59, 2N2221…22, 2N3301…02, 2SC3733+
BSX 49	Mot,Phi,Sie	Si-N	=BSX 48: 60/40V, 30/50ns		2a	TO-18			BSV 59, 2N2221…22, 2N3301…02, 2SC3733+
BSX 50	Sie	Si-N	LF,S, 120/80V, 1A, 5W(Tc=25°), >50MHz, <200/850ns		2a	TO-39			BSS 42…43, BSW 67…68, 2N3019…20, ++
BSX 51	Mot,Tho,Tix	Si-N	LF,S, 25/25V, 0,2A, 0,3W, 300MHz, 70/145ns, hFE>75		2a	TO-18			BSW 41, BSY 62…63, 2N706A, 2N708, ++
BSX 51 A		Si-N	=BSX 51: 50/50V		2a	TO-18			BSV 59, 2N3301…02, 2N3903…04, 2SC3731+
BSX 51 B		Si-N	=BSX 51: 60/60V		2a	TO-18			BSV 59, 2N3301…02, 2N3903…04, 2SC3731+
BSX 52	Mot,Tho,Tix	Si-N	=BSX 51: hFE=180…540		2a	TO-18			BSW 41, BSY 62…63, 2N706A, 2N708, ++
BSX 52 A		Si-N	=BSX 51: 50/50V, hFE=180…540		2a	TO-18			BSV 59, 2N3301…02, 2N3903…04, 2SC3731+
BSX 52 B		Si-N	=BSX 51: 60/60V, hFE=180…540		2a	TO-18			BSV 59, 2N3301…02, 2N3903…04, 2SC3731+
BSX 53(A,B)	Aeg	Si-N	LF,S, 35/30V, 0,1/0,2A, 0,13W, >200MHz, <150/800ns		2a	TO-18			BC 548, BCY 59, BSW 41, BSY 62…63, ++
BSX 54(A,B)	Aeg	Si-N	=BSX 53: 50/45V		2a	TO-18			BC 548, BCY 59, BSW 41, BSY 62…63, ++
BSX 59	Mot,Phi,Tix	Si-N	S,Drv, 70/45V, 1A, 0,8W, >250MHz, 17/45ns		2a	TO-39			BSS 27, BSV 95, 2N3735, 2SC1386, 2SC1635
BSX 60	Mot,Phi,Tix	Si-N	=BSX 59: 70/30V, 17/58ns		2a	TO-39			BSS 27, BSV 95, 2N3735, 2SC1386, 2SC1635
BSX 61	Mot,Phi,Tix	Si-N	=BSX 59: 18/70ns		2a	TO-39			BSS 27, BSV 95, 2N3735, 2SC1386, 2SC1635
BSX 62	Phi,Sie	Si-N	LF,S, 60/40V, 3A, 0,8W, 70MHz, <300/1500ns		2a	TO-39			BSS 45, 2N4238…39, 2N5336…39, 2SC2214
BSX 63	Phi,Sie	Si-N	=BSX 62: 80/60V		2a	TO-39			BSS 45, 2N4238…39, 2N5336…39, 2SC2214
BSX 64	Phi,Sie	Si-N	=BSX 62: 100/80V		2a	TO-39			2N4239, 2N5338…39, 2SC2214
BSX 66	Phi	Si-N	LF,S, 30/20V, 0,1/0,2A, <200/400ns, >200MHz,hFE>40		2a	TO-18			BC 548, BCY 58…59, BSY 62…63, 2N708,++
BSX 67	Phi	Si-N	=BSX 66: hFE=60…350		2a	TO-18			BC 548, BCY 58…59, BSY 62…63, 2N708,++
BSX 68	Aeg,Phi	Si-N	LF,S, 30/15V, 0,1/0,2A, >175MHz,<200/400ns, hFE>30		12a	SOT-33			BC 548, BCY 58…59, BSY 62…63, 2N708,++
BSX 69	Aeg,Phi	Si-N	=BSX 68: 30/20V, hFE=60…180		12a	SOT-33			BC 548, BCY 58…59, BSY 62…63, 2N708,++
BSX 70	Phi,Tix	Si-N	LF,S, 75/30V, 0,5/1A, 0,5W, <70/250ns, hFE>40		2a	TO-18			BC 639, BSW 63…64, 2N2221A…22A, ++
BSX 71	Phi,Tix	Si-N	=BSX 70: hFE=100…300		2a	TO-18			BC 639, BSW 63…64, 2N2221A…22A, ++
BSX 72	Aeg,Tix	Si-N	LF,S, 40/25V, 1/1,5A, 0,7W, >100MHz, 25/150ns		2a	TO-39			BC 140…141, BSW 27…29, 2N3252…53, ++
BSX 73	Aeg	Si-N	HF,S, 60/30V, 0,8A, 0,8W, >250MHz, 25/-ns, hFE>40		2a	TO-39	(BC 337)	7a	BSS 13, BSS 27, BSV 77, 2N5189, 2SC1386
BSX 74	Aeg	Si-N	=BSX 73: hFE=100…300		2a	TO-39	(BC 337)	7a	BSS 13, BSS 27, BSV 77, 2N5189, 2SC1386
BSX 75	Aeg,Tix	Si-N	LF,S, 40/25V, 0,8/1A, 0,43W, >100MHz, 25/150ns		2a	TO-18	BC 337	7a	BC 635, BSW 61…64, 2N2221(A)…22(A), ++
BSX 76	Phi,Tix	Si-N	LF,S, 20/20V, 0,1A, 0,3W, <30/-ns, >50MHz, hFE>35		2a	TO-18			BC 548, BSW 41, BSY 62…63, 2N706A, ++
BSX 77	Phi,Tix	Si-N	=BSX 76: 40/20V, >100MHz, hFE=40…120		2a	TO-18			BC 547, BSW 41, BSY 63, 2N708, 2N4123,++
BSX 78	Phi,Tix	Si-N	=BSX 76: 40/20V, hFE=80…240		2a	TO-18			BC 547, BSW 41, BSY 63, 2N708, 2N4123,++
BSX 79(A,B)	Aeg,Tix	Si-N	LF,S, 50/45V, 0,1/0,2A, 0,375W, >200MHz,<150/800ns		2a	TO-18			BC 547, BCY 59, 2N3903…04, 2SC3731,++
BSX 80	Aeg	Si-N	S, 35/15V, 0,23A, 0,15W, >200MHz, <40/80ns		9e				BSW 41, BSY 63, 2N708, 2N4123, 2SC3731++
BSX 81(A,B)	Aeg	Si-N	LF,S, 35/30V, 0,1A, 0,3W, >200MHz, <150/800ns		9e				BC 548, BSW 41, BSY 63, 2N708, 2N4123,++
BSX 82	Phi	MOS-N-FET-d	Chopper, 30V, 50mA, on=200Ω, off=100MΩ		5m	TO-72			BFX 63
BSX 83	Sgs	MOS-P-FET-e	Chopper, 30V, Up<6V, <250/-ns		5(DGsubS)	TO-72			-
BSX 84	Sgs	MOS-P-FET-e	Chopper, 30V, Up<6V, <250/-ns		5(DGsubS)	TO-72			-
BSX 85	Sgs	MOS-P-FET-e	Dual, Chopper, 30V, 0,2A, Up<6V, <50/-ns		TO-77	D-GsubG-DS			MFE 3020…3021
BSX 86	Sgs	MOS-P-FET-e	Dual, Chopper, 30V, 0,2A, Up<6V, <50/-ns		TO-77	D-GsubG-DS			MFE 3020…3021
BSX 87	Sgs,Tix	Si-N	S, 40/15V, 0,5A, 0,36W, 370MHz, 25/25ns, hFE>30		2a	TO-18			BSS 10, BSX 26, BSX 39, 2N3261, 2SC4648+
BSX 87 A		Si-N	=BSX 87: 9/15ns, 600MHz, hFE>55		2a	TO-18			BSS 10, BSX 26, BSX 39, 2N3261, 2SC4648+
BSX 88	Sgs,Tix	Si-N	S, 40/15V, 0,5A, 0,36W, 400MHz, <40/75ns, hFE>30		2a	TO-18			BSS 10, BSX 26, BSX 39, 2N3261, 2SC4648+
BSX 88 A		Si-N	=BSX 88: <30/70ns, 580MHz, hFE>50		2a	TO-18			BSS 10, BSX 26, BSX 39, 2N3261, 2SC4648+
BSX 89	Mot,Sgs,Tix	Si-N	S, 25/15V, 0,5A, 0,3W, >200MHz, <40/75ns		2a	TO-18			BSS 10, BSX 26, BSX 39, 2N914, 2N3261,++
BSX 90	Mot,Sgs,Tix	Si-N	SS, 20/12V, 0,2A, 0,3W, <12/45ns, >300MHz, hFE>20		2a	TO-18			BSS 10…12, BSX 19…20, 2N2368…69, ++
BSX 91	Mot,Sgs,Tix	Si-N	=BSX 90: hFE=40…120		2a	TO-18			BSS 10…12, BSX 19…20, 2N2368…69, ++
BSX 92	Mot,Sgs,Tix	Si-N	SS, 40/15V, 0,15/0,5A, 0,36W, >400MHz, <12/15ns		2a	TO-18			BSS 10…12, BSX 19…20, 2N2368…69, ++
BSX 93	Mot,Sgs,Tix	Si-N	SS, 40/15V, 0,15/0,5A, 0,36W, >500MHz, <12/18ns		2a	TO-18			BSS 10…12, BSX 19…20, 2N2368…69, ++
BSX 94	Sgs	Si-P	SS, 6/6V, 0,3W, >650MHz, <15/-ns		2a	TO-18			BSX 36
BSX 94 A	Sgs	Si-N	S, 60/30V, 0,4W, 400MHz		2a	TO-18			BSV 59, BSX 49, 2N3301…3302, ++
BSX 95	Phi,Tix	Si-N	LF,S, 75/30V, 0,5/1A, 0,7W, 50/210ns, hFE>40		2a	TO-39			BSW 53…54, BSX 59…61, 2N2218A…19A, ++
BSX 96	Phi,Tix	Si-N	=BSX 95: hFE=100…300		2a	TO-39			BSW 53…54, BSX 59…61, 2N2218A…19A, ++
BSX 97	Tho	Si-N	HF/S, 40/25V, 0,5A, 0,4W, 300Mhz, <30/-ns		2a	TO-18			BSV 59, BSX 48…49, BSX 87…88, 2N914,++
BSX 98	Sie	Si-N	HF,S, 25/15V, 0,2A, 0,25W, >200MHz, <40/-ns		11a	SOT-25			BSW 41, BSY 62…63, 2N706A, 2N4124, ++
BSX 99	Sie	Si-N	HF,S, 25/20V, 0,2A, 0,5W, >200MHz, <50/-ns		11a	SOT-25			BSW 41, BSY 62…63, 2N706A, 2N4124, ++
BSY									
BSY 10	Phi,Tix	Si-N	LF,S, 60V, 0,05A, 0,3W, 180MHz, 17,7/110ns, hFE>45		2a	TO-5			BSW 51…54, 2N2218…19, 2N3299…3300, ++
BSY 11	Phi,Tix	Si-N	=BSY 10: 45V, hFE=60…125		2a	TO-5			BSW 51…54, 2N2218…19, 2N3299…3300, ++
BSY 17	Mot,Sie,Tix	Si-N	SS, 20/12V, 0,2A, 0,35W, >280MHz, 7/25ns, hFE>20		2a	TO-18			BSS10…12, BSX19…20, =2N743, 2N2368…69
BSY 18	Mot,Sie,Tix	Si-N	=BSY 17: hFE=40…120		2a	TO-18			BSS10…12, BSX19…20, =2N744, 2N2368…69
BSY 19	Mot,Phi,Tix	Si-N	S, 40/15V, 0,2A, 0,32W, >300MHz, <40/70ns		2a	TO-18	(BC 546)	7a	BSW 41, BSY 63, =2N708, 2N4123, 2SC3731+
BSY 20	Itt,Mot	Si-N	S, 25/15V, 0,05A, 0,3W, >200MHz, <40/75ns		2a	TO-18			BSW 41, BSY 62…63, =2N706B, 2N4123, ++
BSY 21	Aeg,Itt,Mot	Si-N	=2N914		2a	TO-18			›2N914
BSY 22	Itt,Mot	Si-N	=2N916		2a	TO-18			›2N916
BSY 23	Itt,Mot	Si-N	=2N834		2a	TO-18			›2N834
BSY 24	Itt,Tix	Si-N	LF,S, 40/20V, 0,5/1,5A, 0,6W, 19/375ns, hFE>15		2a	TO-5			BSW 51…54, 2N3299…3300, 2N2218…2219
BSY 25	Itt,Tix	Si-N	=BSY 24: 16/325ns, hFE=40…100		2a	TO-5			BSW 51…54, 2N3299…3300, 2N2218…2219
BSY 26	Itt,Tix	Si-N	SS, 20/15V, 0,1/0,2A, 0,3W, 300MHz,20/31ns, hFE>15		2a	TO-18			BSV 89…92, BSX 92…93, 2N3011, 2SC3811+

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BSY 27	Itt,Tix	Si-N	=BSY 26: 19/35ns, hFE=25…120		2a	TO-18			BSV 89…92, BSX 92…93, 2N3011, ++
BSY 28	Itt,Tix	Si-N	SS, 15/12V, 0,1/0,2A, 0,3W, 380MHz,14/22ns, hFE>20		2a	TO-18			BSV 89…92, BSX 44, BSX 92…93, 2N3011++
BSY 29	Itt,Tix	Si-N	=BSX 28: 12/20ns, hFE=40…120		2a	TO-18			BSV 89…92, BSX 44, BSX 92…93, 2N3011++
BSY 30	Sie	Si-N	S, 15/15V, 0,2A, 0,3W, <120/-ns, hFE>20		2a	TO-18			BSW 41, BSY 62…63, 2N706A, 2N4123, ++
BSY 31	Sie	Si-N	=BSY 30: <180/-ns, hFE>30		2a	TO-18			BSW 41, BSY 62…63, 2N706A, 2N4123, ++
BSY 32	Itt	Si-N	S, 20/15V, 0,1A, 0,1W, <27/130ns, >200MHz, hFE=32						BSW 41, BSY 62…63, 2N706A, 2N4123, ++
BSY 33	Itt	Si-N	=BSY 32: hFE=55						BSW 41, BSY 62…63, 2N706A, 2N4123, ++
BSY 34	Phi,Sie	Si-N	S,Drv, 60/40V, 0,6A, 0,8W, 400MHz, 30/50ns		2a	TO-39	(BC 141)	2a	BSS 27, BSV 77, BSV 95, 2SC1385…86, ++
BSY 35	Itt	Si-P	Min, S, 75V, 0,05A		Chip	TO-122			-
BSY 36	Itt	Si-N	S, 15/12V, 0,1A, 0,1W, >300MHz, <20/30ns						BSV 89…92, BSX 44, BSX 92…93, 2N3011++
BSY 38(A)	Mot,Phi,Tix	Si-N	=2N743		2a	TO-18			›2N743
BSY 39(A)	Mot,Phi,Tix	Si-N	=2N744		2a	TO-18			›2N744
BSY 40	Mot,Phi,Tix	Si-P	S, 25/20V, 0,1A, 0,3W, 210MHz, <25/100ns, hFE>20		2a	TO-18			2N3250…51, 2N3905…06, 2N4125…26
BSY 41	Mot,Phi,Tix	Si-P	=BSY 40: 230MHz, hFE=50…200		2a	TO-18			2N3250…51, 2N3905…06, 2N4125…26
BSY 42	Itt	Si-N	Dual, 20V, 0,2A, >200MHz		TO-77				-
BSY 43	Itt	Si-N	Dual, 15V, 0,2A, >300MHz		TO-77				-
BSY 44	Aeg,Mot,Tix	Si-N	=2N1613		2a	TO-5			›2N1613
BSY 45	Aeg,Mot,Tix	Si-N	=2N1893		2a	TO-5			›2N1893
BSY 46	Aeg,Mot,Tix	Si-N	=2N2193		2a	TO-5			›2N2193
BSY 47	Itt	Si-N	S, 20/15V, 0,1A, 0,1W, >200MHz, <27/130ns						BSW 41, BSY 62…63, 2N706A, 2N4124, ++
BSY 48	Sie	Si-N	S, 50/25V, 0,6A, 0,4W, >250MHz, <65/-ns		2a	TO-18			BSV 59, BSX 48, 2N2221…22, 2N3301…02++
BSY 49	Sie	Si-N	S, 60/40V, 0,6A, 0,4W, >250MHz, <50/-ns		2a	TO-18			BSV 59, BSX 49, 2N2221…22, 2N3301…02++
BSY 50	Itt	Si-N	S, 15/12V, 0,1A, 0,1W, >350MHz, <20/30ns						BSV 89…92, BSX 44, BSX 92…93, 2N3011++
BSY 51	EUR	Si-N	LF,S, 60/25V, 0,5A, 0,8W, 100MHz, hFE=40…120		2a	TO-39	BC 141	2a	BC 140…141, BC 300…302, =2N697, ++
BSY 52	EUR	Si-N	=BSY 51: hFE=100…300		2a	TO-39	BC 141	2a	BC 140…141, BC 300…302, =2N1420, ++
BSY 53	EUR	Si-N	LF,S, 75/30V, 0,75A, 0,8W, 100MHz, hFE=40…120		2a	TO-39	BC 141	2a	BC 140…141, BC 300…301, =2N1613, ++
BSY 54	EUR	Si-N	=BSY 53: hFE=100…300		2a	TO-39	BC 141	2a	BC 140…141, BC 300…301, =2N1711, ++
BSY 55	EUR	Si-N	LF,S, 120/80V, 0,5A, 0,8W, 100MHz, hFE=40…120		2a	TO-39			BC 300, BSW 67…68, BSX 47, =2N1893, ++
BSY 56	EUR	Si-N	=BSY 55: hFE=100…300		2a	TO-39			BC 300, BSW 67…68, BSX 47, 2N1893, ++
BSY 58	Phi,Sie	Si-N	S,Drv, 50/25V, 0,6A, 0,8W, 400MHz, 35/65ns		2a	TO-39			BSS 27…29, BSV 77, 2N3724A, 2SC1386, ++
BSY 59	Sie	Si-P	S, 30/30V, 0,8A, 0,28W, 100MHz, <500/850ns		11a	SOT-25			BC 327…328, BC 636, 2N2906…2907, ++
BSY 61(Y)	Sie	Si-N	S, 25V, 0,2A(Y=50mA), 0,2W, >200MHz, <40/75ns		7c	TO-92			BSW 41, BSY 62…63, 2N706A, 2N4124, ++
BSY 62(A,B)	Sie,Tix	Si-N	S, 25/15V, 0,2A, 0,35W, >280MHz, <40/75ns		2a	TO-18			BSW 41, =2N706A, 2N708, 2N4123…24, ++
BSY 63	Phi,Sie,Tix	Si-N	S, 40/15V, 0,2A, 0,35W, >300MHz, <40/75ns		2a	TO-18			BSW 41, =2N708, 2N3903…04, 2N4123, ++
BSY 65	Itt	Si-N	LF,S, 15V, 0,1A, 0,3W, 200MHz		2a	TO-18			BC 548, BCY 58…59, BSW 41, 2N706A, ++
BSY 66	Itt	Si-N	10V, 0,05W						-
BSY 67	Itt	Si-N	10V, 0,05W						-
BSY 68	Phi,Tix	Si-N	Nixie Drv, 120/80V, 0,05A, 0,6W, >20MHz		2a	TO-39			BF 257…259, BF 657…659, 2N5058…5059
BSY 70	Aeg,Mot,Tix	Si-N	=2N706		2a	TO-18			›2N706
BSY 71	Aeg,Mot,Tix	Si-N	=2N1711		2a	TO-5			›2N1711
BSY 72	Itt,Tix	Si-N	LF,S, 25/18V, 0,03A, 0,3W, 170MHz, F<5dB(1kHz)		2a	TO-18			BC 169, BC 184, BC 239, BC 549, 2SC2675+
BSY 73	Itt,Tix	Si-N	LF,S, 25/18V, 0,1A, 0,3W, 145MHz, F<12dB(1kHz)		2a	TO-18			BC 168, BC 183, BC 238, BC 548, 2SD767++
BSY 74	Itt,Tix	Si-N	LF,S, 25/18V, 0,1A, 0,3W, 170MHz, F<12dB(1kHz)		2a	TO-18			BC 168, BC 183, BC 238, BC 548, 2SD767
BSY 75	Itt,Tix	Si-N	LF,S, 40/32V, 0,25A, 0,3W, 145MHz, F<12dB(1kHz)		2a	TO-18			BC 167, BC 182, BC 237, BC 547, 2SD767++
BSY 76	Itt,Tix	Si-N	=BSY 75: 170MHz		2a	TO-18			BC 167, BC 182, BC 237, BC 547, 2SD767++
BSY 77	Itt,Tix	Si-N	=BSY 75: 80/64V		2a	TO-18			BC 546, 2SC2240, 2SC2459, 2SC2674…75,++
BSY 78	Itt,Tix	Si-N	=BSY 75: 80/64V, 170MHz		2a	TO-18			BC 546, 2SC2240, 2SC2459, 2SC2674…75,++
BSY 79	Itt,Tix	Si-N	Nixie Drv, 120V, 0,03A, 0,3W, 100MHz		2a		BF 420 A	7c	BF 297…299, BF 422, BSS 38, BSX 21, ++
BSY 80	Itt,Tix	Si-N	LF,S, 25/18V, 0,1A, 0,3W, 210MHz, F<12dB(1kHz)		2a	TO-18			BC 168, BC 183, BC 238, BC 548, 2SD767++
BSY 81	Itt,Tix	Si-N	LF,S, 40/18V, 1A, 0,9W, 100MHz, hFE=40…120		2a	TO-39	BC 141	2a	BC 140…141, BSW 65…68, BSX 45…47, ++
BSY 82	Itt,Tix	Si-N	=BSY 81: 120MHz, hFE=100…300		2a	TO-39	BC 141	2a	BC 140…141, BSW 65…68, BSX 45…47, ++
BSY 83	Itt,Tix	Si-N	=BSY 81: 80/35V		2a	TO-39	BC 141	2a	BC 140…141, BSW 65…68, BSX 45…47, ++
BSY 84	Itt,Tix	Si-N	=BSY 81: 80/35V, 120MHz, hFE=100…300		2a	TO-39	BC 141	2a	BC 140…141, BSW 65…68, BSX 45…47, ++
BSY 85	Itt,Tix	Si-N	=BSY 81: 120/64V, 110MHz		2a	TO-39	BC 141	2a	BSS 42…43, BSW 67…68, BSX 47, 2N2102++
BSY 86	Itt,Tix	Si-N	=BSY 81: 120/64V, 130MHz, hFE=100…300		2a	TO-39	(BC 141)[7]	2a	BSS 42…43, BSW 67…68, BSX 47, 2N2102++
BSY 87	Itt,Tix	Si-N	LF,S, 100/60V, 0,5A, 0,8W, 100MHz, hFE=40…120		2a	TO-39	BC 141	2a	BC 141, BC 300, BSW 66…68, BSX 46…47++
BSY 88	Itt,Tix	Si-N	=BSY 87: 145MHz, hFE=100…300		2a	TO-39	BC 141	2a	BC 141, BC 300, BSW 66…68, BSX 46…47++
BSY 89	Itt,Tix	Si-N	LF,S, Chopper, 25/18V, 0,1A, 0,3W, 80/-ns		2a	TO-18			-
BSY 90	Itt,Tix	Si-N	LF,S, 60/25V, 0,5A, 0,8W, 170MHz, F<8dB(1kHz)		2a	TO-39	BC 141	2a	BC 140…141, BC 300…302, 2N2218…19, ++
BSY 91	Aeg,Itt,Tix	Si-N	LF,S, 40/25V, 0,3A, 0,8W, >50MHz, F<15dB(1kHz)		2a	TO-39			BC 140…141, BC 300…302, 2N2218…19, ++
BSY 92	Aeg,Tix	Si-N	=BSY 91: 60/40V		2a	TO-39			BC 140…141, BC 300…302, 2N2218…19, ++
BSY 93	Aeg,Tix	Si-N	=BSY 91: 60/40V, 0,36W		2a	TO-18			BC 337, BC 637, BSV 59, 2N2221…22, ++
BSY 95(A)	Phi,Tix,++	Si-N	HF,S, 20/15V, 0,1A, 0,3W, >200MHz		2a	TO-18			BSW 42, BSY 62…63, 2N706A, 2N4124, ++
BSYP 62	Ucp	Si-N	NF,S, 25V, 0,2A, 0,36W, 200MHz		2a	TO-18L			-
BSYP 63	Ucp	Si-N	NF,S, 40V, 0,2A, 0,36W, 300MHz		2a	TO-18L			-
BT									
BT		Si-P	=2SB1048 (SMD-Marking)		39	SOT-89			›2SB1048
BT		Si-N	=2SC4069 (SMD-Marking)		35	SOT-23			›2SC4069
BT		Si-P	=BCW 61RE (SMD-Marking)		35	SOT-23			›BCW 61RE
BT 1		Si-P	=BSP 15 (SMD-Marking)		=39°	SOT-223			›BSP 15
BT 1		Si-P	=BST 15 (SMD-Marking)		39	SOT-89			›BST 15
BT 2		Si-P	=BSP 16 (SMD-Marking)		=39°	SOT-223			›BSP 16
BT 2		Si-P	=BST 16 (SMD-Marking)		39	SOT-89			›BST 16
BT 100 A/….R	Phi	50Hz-Thy	300…500V, 2A(Tc=75°), 4,5A=, Igt/Ih<10/<15mA		13k	TO-202	TAG 626-600[4]	17e	(TAG 631…, TAG 632…, TAG 621…,++)[4]
BT 101/300…500 R	Phi	50Hz-Thy	300…500V, 6,5A(Tc=85°), 15A=, Igt<10		21b	TO-64			-
BT 102/…R	Phi	50Hz-Thy	=BT 101/…R: Igt<50mA		21b	TO-64			BTW 42/…
BT 103	Itt	GTO-Thy	1100V, 2,6A(Tc=85°C), Igt<100mA, <1µs		22a	TO-66			-
BT 104	Itt	GTO-Thy	1200V, 3A(Tc=85°C), Igt<100mA, <1µs		22a	TO-66			-
BT 105	Itt	GTO-Thy	600V, 2,7A(Tc=85°C), Igt<100mA, <1µs		22a	TO-66			-
BT 106	Phi	F-Thy	700V, 1A(Tc=90°C), Igt/Ih<20/<25mA, 17µs		21b	TO-64			-
BT 106 A….D	Phi	50Hz-Thy	100…400V, 4A=, Igt/Ih<0,2/<3mA A=100V, B=200V, C=300V, D=400V		14e	TO-126	TIC 106 M[4]	16e	C 106 A, 2N6236…6241, (TIC 106…)[4]
BT 107	Phi	Thy	500V, 6,5A(Tc=60°C), Igt<10mA		21b	TO-64			-
BT 108	Phi	Thy	500V, 6,5A(Tc=60°C), Igt<50mA		21b	TO-64			BTW 42/600
BT 109	Phi	Thy	500V, 6,5A(Tc=75°C), Igt/Ih<10/<50mA		21b	TO-64			-
BT 109/….R		Thy					TAG 626-600	17e	BST C0246
BT 110	Phi	Thy	400V, 6A(Tc=75°C), Igt/Ih<35/<20mA						-
BT 112/750R	Tho	F-Thy	TV-HA, 750V, 3,2A(Tc=60°), 5A=, Igt<50mA, <2,4µs		22a	TO-66	TD 3FP 800H1*	17f	S 3703 SF, TU 3F 800H, (TD 3F 800 H)[1]
BT 113/700R	Tho	F-Thy	TV-HA, 700V, 3,2A(Tc=60°), 5A=, Igt<50mA, <4,5µs		22a	TO-66	TD 3FP 800R1*	17f	S 3702 S, S 6080 C, (TD 3F 800 R)[1]
BT 114	Ssc	F-Thy	TV-HA, 750V, 3,2A(Tc=60°), Igt<50mA, <2,4µs				TD 3FP 800H1*	17f	S 3703 SF, TU 3F 800H, (TD 3F 800 H)[1]
BT 114	Ssc	F-Thy	TV-HA, 700V, 3,2A(Tc=60°), Igt<50mA, <4,5µs				TD 3FP 800R1*	17f	S 3702 S, S 6080 C, (TD 3F 800 R)[1]
BT 116	Phi	Thy	750V, 1A(Tc=100°C), 15A=, Igt<20mA						-

Original	Fabric.	Constr.	Info (Compl.	Fig.		JAEGER	Fig.	International
BT 117	Ssc	F-Thy	TV-HA, 750V, 3,2A(Tc=60°C), Igt<50mA, <2,4µs	17e	TO-220	17088[1]*	17e	BStC12 50, (17088)[1]
BT 118	Ssc	F-Thy	TV-HA, 750V, 3,2A(Tc=60°C), Igt<50mA, <4,2µs	17e	TO-220	17089[1]*	17e	BT 154, (BStCC02 53R, 17089)[1]
BT 119	Itt	F-Thy	TV-HA, 750V, 3A, Igt/Ih<40/<100mA, <2,4µs	22a	TO-66	TD 3FP 800H[1]*	17f	S 3703, TU 3F 800 H, (TD 3F 800 H)[1]
BT 120	Itt	F-Thy	TV-HA, 700V, Igt/Ih<40/<100mA, <4,5µs	22a	TO-66	TD 3FP 800R[1]*	17f	(TD 3F 800 R, TD 4F 800 R,)[1]
BT 121	Itt	F-Thy	TV-HA, 500V, 2,8A, Igt/Ih<40/100mA, <2,4µs	22a	TO-66	TD 3FP 800H[1]*	17f	S 3705, S 3703, TU 3F500H, (TD 3F500H)[1]
BT 122	Itt	F-Thy	Strobo Flash, 500V, 2,8A, Igt/Ih<40/<100mA, <2,4µs	22a	TO-66	TD 3FP 800H[1]*	17f	BSt C09 30T92, BStE04…T, (TD 3F 500 H)[1]
BT 123	Phi	Triac	500V, 15A(Tc=70°C), Igt/Ih<35/<50mA	16j	TO-127			(TAG 257-500)[4]
BT 124	Phi	F-Thy	500V, 4,5A(Tc=85°C), Igt/Ih<15/<25mA, <3µs	16e	TO-127			-
BT 125/700 R	Phi	F-Thy	TV-HA, 700V, 3,2A(Tc=85°), 5A=, Igt<40mA, <4,5µs	22a	TO-66	TD 3FP 800R[1]*	17f	S 3702, S 6080 C, (TD 3F 700 R)[1]
BT 126/750 R	Phi	F-Thy	TV-HA, 750V, 3,2A(Tc=85°), 5A=, Igt<40mA, <2,4µs	22a	TO-66	TD 3FP 800H[1]*	17f	S 3703, TU 3F 800 H, (TD 3F 800 H)[1]
BT 127/….(R)	Phi	F-Thy	350…750V, 3,2A(Tc=85°), 5A=,Igt/Ih<40/<50mA,<10µs	22a	TO-66	(TAG 626-600)[5]	17e	TAG 670S-…, TAG 675S-…
BT 128/700 R	Phi	F-Thy+Di	TV-HA, 700V, 3,2A(85°), 5A=, Igt<40mA, <4,5µs	22a	TO-66	TD 3FP 800R*	17f	S 6087 A, BSt CC01 46R, TD 3F 800 R
BT 129/….R	Phi	F-Thy+Di	TV-HA,600…750V, 3,2A(Tc=85°),5A=, Igt<40mA,<2,4µs	22a	TO-66	TD 3FP 800H*	17f	BStCC0140…0153H, S 6087B, TD 3F…H
BT 132	Phi	Thy	-700/+400V, 1A(Tc=85°C), Igt<50mA	21b	TO-64			(BTW 42/…)
BT 133	Phi	Thy	=BT 132: -100/+400V	21b	TO-64			(BTW 42/…)
BT 134/…	Phi	Triac	500…800V, 4A=(Tc=102°C), Igt/Ih<70/<15	=14j	SOT-82			-
BT 134/…B		Triac	=BT 134/…: Igt/Ih<10/<10mA	=14j	SOT-82			-
BT 134/…E		Triac	=BT 134/…: Igt/Ih<25/<15mA	=14j	SOT-82			-
BT 134/…F		Triac	=BT 134/…: Igt/Ih<70/<15mA	=14j	SOT-82			-
BT 134/…G		Triac	=BT 134/…: Igt/Ih<100/<30mA	=14j	SOT-82			-
BT 134W/…		Triac	500…800V, 1A(Tc=77°C), Igt/Ih<35/<15	=39°j	SOT-223			-
BT 136/….	Phi	Triac	500…800V, 2,5A(Tc=92°), 4A=, Igt/Ih<70/<30mA	17j	TO-220	TAG 232-600	17j	TXC10H…, TAG 230-…, TAG 231-…,++
BT 136/….D		Triac	=BT 136/…: Igt/Ih<10/<15mA	17j	TO-220	TAG 232-600	17j	TXC18G…, TAG 232-…, TAG 221-…,++
BT 136/….E		Triac	=BT 136/…: Igt/Ih<25/<20mA	17j	TO-220	TAG 232-600	17j	TAG 231-…, TAG 220-…, TAG 225-…, ++
BT 136/….F		Triac	=BT 136/…: Igt/Ih<70/<30mA	17j	TO-220	TAG 232-600	17j	TXC10H…, TAG 230-…, TAG 231-…, ++
BT 136/….G		Triac	=BT 136/…: Igt/Ih<100/<45mA	17j	TO-220	TAG 232-600	17j	TXC10H…, TAG 230-…, TAG 224-…, ++
BT 137/….	Phi	Triac	500…800V, 5A(Tc=87°), 8A=, Igt/Ih<70/<45mA	17j	TO-220			TAG 224-…, MAC 222A-…, TXD10H…, ++
BT 137/….D		Triac	=BT 137/…: Igt/Ih<10/<20mA	17j	TO-220			TAG 226-…, MAC 228A-…
BT 137/….E		Triac	=BT 137/…: Igt/Ih<25/<35mA	17j	TO-220			TAG 225-…, TAG 252-…, TAG 255-…, ++
BT 137/….F		Triac	=BT 137/…: Igt/Ih<70/<45mA	17j	TO-220			TAG 224-…, MAC 222A-…, TXD10H…, ++
BT 137/….G		Triac	=BT 137/…: Igt/Ih<100/<60mA	17j	TO-220			TAG 224-…, MAC 222A-…, TXD10H…, ++
BT 138/….	Phi	Triac	500…800V, 7,5A(Tc=83°), 12A=, Igt/Ih<70/<60mA	17j	TO-220			TAG 255-…, TAG 256-…, TXD10H…P, ++
BT 138/….E		Triac	=BT 138/…: Igt/Ih<25/<40mA	17j	TO-220			TAG 257-…
BT 138/….F		Triac	=BT 138/…: Igt/Ih<70/<60mA	17j	TO-220			TAG 255-…, TAG 256-…, TXD10H…P, ++
BT 138/….G		Triac	=BT 138/…: Igt/Ih<100/<90mA	17j	TO-220			TAG 255-…, TAG 256-…, TXD10H…P, ++
BT 139/….	Phi	Triac	500…800V, 10A(Tc=79°), 16A=, Igt/Ih<70/<60mA	17j	TO-220			MAC 15A-…, TAG 280-…, TAG 281-…, ++
BT 139/….E		Triac	=BT 139/…: Igt/Ih<25/<40mA	17j	TO-220			-
BT 139/….F		Triac	=BT 139/…: Igt/Ih<70/<60mA	17j	TO-220			MAC 15A-…, TAG 280-…, TAG 281-…, ++
BT 139/….G		Triac	=BT 139/…: Igt/Ih<100/<90mA	17j	TO-220			MAC 15A-…, TAG 280-…, TAG 281-…, ++
BT 143/400 R	Phi	F-Thy+Di	Strobo Flash, 400V, 3,2A(Tc=85°C), Igt<40mA, <10µs	22a	TO-66	17088…17089*	17f	BStCC 0126T91…0153T91, BT 127/750 R
BT 145/…R	Phi	Thy	500…800V, 16A=(Tc=92°), Igt/Ih<35/<60mA	17e	TO-220			2N6400…6405, BStD10…M, T9,5N…,CS 15…
BT 146	Phi	Thy	500V, 15A=, Igt<35mA	22a	TO-66			2N6404, 2N6405, T9,5N…, BT 152/…, ++
BT 148	Phi	Thy	500V, 6,5A(Tc=60°C), Igt<35mA	22a	TO-66			2N6404, 2N6405, TIC 122D…E
BT 148W/…	Phi	Thy	400…600V, 0,6A(Tc=84°), Igt/Ih<0,2/<6	=39°e	SOT-223			-
BT 149 A…M	Phi	50Hz-Thy	50…600V, 0,6A(Tc=55°), 1A=, Igt/Ih<0,2/<5mA, 50µs A=100V, B=200V, D=400V, E=500V, F=50V, M=600V	7a	TO-92	BRX 49	7a	TAG 59…, MCR 606-2…8, 2N6681…6685, ++
BT 150	Phi	Thy	500V, 2,5A(Tc=98°C), 4A=, Igt/Ih<0,2/<6mA	17e	TO-220	TIC 106 M	17e	TIC106E, TAG623-500, TAG628-500, S4060E
BT 151/…. R	Phi	F-Thy	500…800V, 7,5A(Tc=95°), 12A=, Igt/Ih<15/<20mA,2µs	17e	TO-220			-
BT 151F/…		F-Thy	=BT 151/…R: Iso, 9A=	17b	TO-220Iso			-
BT 152/… R	Phi	50Hz-Thy	400…800V, 13A(Tc=93°), 20A=, Igt/Ih<32/<60mA,35µs	17e	TO-220			2N6504…6509
BT 153	Phi	F-Thy	TV-VA, 500V, 4A(Tc=95°),6A=,Igt/Ih<40/<100mA,<20µs	17e	TO-220			(BT 154)
BT 154	Phi	F-Thy	TV-HA, 750V, 4A(Tc=85°), 8A=, Igt<40mA, <2,4µs	17e	TO-220			-
BT 155/…RK	Phi	F-Thy	600…800V,6,5A(Tc=85°),15A=,Igt/Ih<100/<200mA,<6µs	17e	TO-220			-
BT 155/…RN		F-Thy	=BT 155/…RK: <9µs	17e	TO-220			-
BT 155/…RP		F-Thy	=BT 155/…RK: <12µs	17e	TO-220			-
BT 157/…R	Phi	GTO-Thy	+1300…+1500V, 2,2A(Tc=80°C), Igt<200mA	17e	TO-220			BTW 58/1300…1500
BT 158/…	Mot	Triac	400…600V, 4A(Tc=90°), 8A=, Igt/Ih<40/<30mA	17j	TO-220			T 2806…, T 2856…, BT 162/…, ++
BT 162/…	Mot	Triac	400…600V, 6A(Tc=95°), 12A=, Igt/Ih<40/<30mA	17j	TO-220			T 6006…, TAG 257-…
BT 169 B…G	Phi	F-Thy	200…600V, 0,52A(Tc=55°), 0,8A=, Igt/Ih<0,2/<5mA B=200V, D=400V, E=500V, G=600V	7n	TO-92	BRX 49	7a	BRX 47…49, BRY 55S/200…800
BT 500	Mot	Si-N	Vorspg.-Stabi f. Sender/RF Bias Source f. AB Amp.	49a	TO-60			-
BT 500 A		Si-N	=BT 500:	59r	SOT-121			-
BTA								
BTA 04-…A	Tho	Triac	200…800V, 4A=(Tc=75°), Igt/Ih<25/<25mA	17l	TO-220Iso	(TAG 232-600)[3]	17j	TAG 421…, (TAG 231…, TAG 220…)[3]
BTA 04-….D		Triac	=BTA 04-…A: Igt/Ih<10/<15mA	17l	TO-220Iso	(TAG 232-600)[3]	17j	(TXC 18H…, TIC 216…, TAG 232…,)[3]
BTA 04-….GP		Triac	=BTA 04-…A: Igt/Ih<75/<13mA	17l	TO-220Iso	(TAG 232-600)[3]	17j	(TXC 18H…, TIC 216…, TAG 232…,)[3]
BTA 04-….S		Triac	=BTA 04-…A: Igt/Ih<10/<25mA	17l	TO-220Iso	(TAG 232-600)[3]	17j	(TAG 232…, TAG 231…, TXC 18G…,)[3]
BTA 04-….T		Triac	=BTA 04-…A: Igt/Ih<5/<15mA	17l	TO-220Iso	(TAG 232-600)[3]	17j	(TAG 233…, TXC 18D…, TAG 222-…,)[3]
BTA 06-….A	Tho	Triac	200…800V, 6A=(Tc=75°), Igt/Ih<25/<25mA	17l	TO-220Iso			TAG 421…, (TAG 220…, TAG 225…)[3]
BTA 06-….B		Triac	=BTA 06-…A: Igt/Ih<100/<50mA	17l	TO-220Iso			TAG 420…, (TAG 224…, TXC 10H…M)[3]
BTA 06-….C		Triac	=BTA 06-…A: Igt/Ih<50/<25mA	17l	TO-220Iso			TAG 420…, (TAG 224…, TXC 10H…M)[3]
BTA 06-….D		Triac	=BTA 06-…A: Igt/Ih<10/<15mA	17l	TO-220Iso			(TAG 221…, TXC 18G…M, TAG 226…)[3]
BTA 06-….GP		Triac	=BTA 06-…A: Igt/Ih<75/<13mA	17l	TO-220Iso			(MAC 216…, T 2801…, BS 7-…A, SC 141.)[3]
BTA 06-….S		Triac	=BTA 06-…A: Igt/Ih<10/<25mA	17l	TO-220Iso			(TAG 221…, TXC 18G…M, TAG 226…)[3]
BTA 06-….T		Triac	=BTA 06-…A: Igt/Ih<5/<15mA	17l	TO-220Iso			(TAG 222…, TXC 18D…M, TAG 227…)[3]
BTA 06-…AW,BW,CW		Triac	=BTA 06-…A,B,C: snubberless di/dt	17l	TO-220Iso			-
BTA 06-…SW,TW		Triac	=BTA 06-…S,T: LogL	17l	TO-220Iso			-
BTA 08-….A	Tho	Triac	200…800V, 8A=(Tc=75°), Igt/Ih<25/<25mA	17l	TO-220Iso			TAG 426…, TAG 452…, TAG 457…
BTA 08-….B		Triac	=BTA 08-…A: Igt/Ih<100/<50mA	17l	TO-220Iso			TAG 425…, TAG 451…, TAG 456…
BTA 08-….C		Triac	=BTA 08-…A: Igt/Ih<50/<25mA	17l	TO-220			TAG 425…, TAG 451…, TAG 456…
BTA 08-….S		Triac	=BTA 08-…A: Igt/Ih<10/<25mA	17l	TO-220Iso			(TAG 226…, MAC 228A-…)[3]
BTA 08-…AW,BW,CW		Triac	=BTA 08-…A,B,C: snubberless di/dt	17l	TO-220Iso			-
BTA 08-…SW,TW		Triac	=BTA 08-…S: LogL, TW: Igt/Ih<5/<15mA	17l	TO-220Iso			-
BTA 10-….B	Tho	Triac	200…800V, 10A=(Tc=75°), Igt/Ih<100/<50mA	17l	TO-220Iso			TAG 456…, TAG 480…, TAG 481…
BTA 10-….C		Triac	=BTA 10-…B: Igt/Ih<50/<25mA	17l	TO-220Iso			TAG 456…, TAG 480…, TAG 481…
BTA 10-…AW,BW,CW		Triac	=BTA 10-…: snubberless di/dt AW: Igt/Ih<75/<75, BW: <50/<50, CW: <35/<35mA	17l	TO-220Iso			-
BTA 12-….B	Tho	Triac	200…800V, 12A=(Tc=75°), Igt/Ih<100/<50mA	17l	TO-220Iso			TAG 480…, TAG 481…
BTA 12-….C		Triac	=BTA 12-…B: Igt/Ih<50/<25mA	17l	TO-220Iso			TAG 480…, TAG 481…
BTA 12-…AW,BW,CW		Triac	=BTA 12-…: snubberless di/dt AW: Igt/Ih<75/<75, BW: <50/<50, CW: <35/<35mA	17l	TO-220Iso			-
BTA 13-….B	Tho	Triac	200…800V, 12A=, Igt/Ih<50/<50mA	17l	TO-220Iso			TAG 480…, TAG 481…

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
BTA 16-....B	Tho	Triac	200...800V, 16A=(Tc=75°), Igt/Ih<100/<50mA		17l	TO-220Iso		(MAC 15A..., BT 139/..., TAG 280...)[3]
BTA 16-....C		Triac	=BTA 16-...B: Igt/Ih<50/<25mA		17l	TO-220Iso		(MAC 15A..., BT 139/..., TAG 280...)[3]
BTA 16-...AW,BW,CW		Triac	=BTA 16-...: snubberless di/dt AW: Igt/Ih<75/<75, BW: <50/<50, CW: <35/<35mA		17l	TO-220Iso		-
BTA 20-...AW	Tho	Triac	Snubberless, 400...800V, 20A=, Igt/Ih<75/<100mA		17l	TO-220Iso		-
BTA 20-...BW		Triac	=BTA 20-...AW: Igt/Ih<50/<75mA		17l	TO-220Iso		-
BTA 20-...CW		Triac	=BTA 20-...AW: Igt/Ih<35/<50mA		17l	TO-220Iso		-
BTA 20 C	Rca	Triac	300V, 6A=(Tc=80°), Igt/Ih<80/<100mA		17j	TO-220		TXC 10L40M, TW7N400, TIC 226C, ++
BTA 20 D		Triac	=BTA 20C: 400V		17j	TO-220		TXC 10L40M, TW7N400, TIC226D, ++
BTA 20 E		Triac	=BTA 20C: 500V		17j	TO-220		TXC 10L50M, TW7N600, TIC226E, ++
BTA 20 M		Triac	=BTA 20C: 600V		17j	TO-220		TXC 10L60M, TW7N600, TIC226M, ++
BTA 20 N		Triac	=BTA 20C: 800V		17j	TO-220		TXC 10L80M, TW7N800, TIC226N, ++
BTA 21 C	Rca	Triac	300V, 8A=(Tc=80°), Igt/Ih<35/<100mA		17j	TO-220		TAG 225-..., TAG 257-...
BTA 21 D		Triac	=BTA 21C: 400V		17j	TO-220		TAG 225-..., TAG 257-...
BTA 21 E		Triac	=BTA 21C: 500V		17j	TO-220		TAG 225-..., TAG 257-...
BTA 21 M		Triac	=BTA 21C: 600V		17j	TO-220		TAG 225-..., TAG 257-...
BTA 21 N		Triac	=BTA 21C: 800V		17j	TO-220		TAG 225-..., TAG 257-...
BTA 22 B	Rca	Triac	200V, 10A=(Tc=75°), Igt/Ih<60/<30mA		17j	TO-220		TAG 250-..., TAG 251-..., TXD 10H40M, ++
BTA 22 C		Triac	=BTA 22B: 300V		17j	TO-220		TAG 250-..., TAG 251-..., TXD 10H40M, ++
BTA 22 D		Triac	=BTA 22B: 400V		17j	TO-220		TAG 250-..., TAG 251-..., TXD 10H40M, ++
BTA 22 E		Triac	=BTA 22B: 500V		17j	TO-220		TAG 250-..., TAG 251-..., TXD 10H50M, ++
BTA 22 M		Triac	=BTA 22B: 600V		17j	TO-220		TAG 250-..., TAG 251-..., TXD 10H60M, ++
BTA 22 N		Triac	=BTA 22B: 800V		17j	TO-220		TAG 250-..., TAG 251-..., TXD 10H80M, ++
BTA 23 B	Rca	Triac	200V, 12A=(Tc=70°), Igt/Ih<60/<30mA		17j	TO-220		TAG 255-..., TAG 256-..., BT 138/..., ++
BTA 23 C		Triac	=BTA 23B: 300V		17j	TO-220		TAG 255-..., TAG 256-..., BT 138/..., ++
BTA 23 D		Triac	=BTA 23B: 400V		17j	TO-220		TAG 255-..., TAG 256-..., BT 138/..., ++
BTA 23 E		Triac	=BTA 23B: 500V		17j	TO-220		TAG 255-..., TAG 256-..., BT 138/..., ++
BTA 23 M		Triac	=BTA 23B: 600V		17j	TO-220		TAG 255-..., TAG 256-..., BT 138/..., ++
BTA 23 N		Triac	=BTA 23B: 800V		17j	TO-220		TAG 255-..., TAG 256-..., BT 138/..., ++
BTA 25-....A	Tho	Triac	200...700V, 25A=(Tc=65°), Igt/Ih<150/<100mA		64l	(RD91)		(BTW 41/...)[3]
BTA 25-....B		Triac	=BTA 25-...A: Igt/Ih<80/<80mA		64l	(RD91)		(MAC 525A...,TAG 725-..., TAG 726-...)[3]
BTA 26-....A	Tho	Triac	200...800V, 25A=(Tc=75°), Igt/Ih<150/<100mA		18l	TO-3P Iso		BTA 41-...
BTA 26-....B		Triac	=BTA 26-...A: Igt/Ih<100/<80mA		18l	TO-3P Iso		BTA 41-...
BTA 26-...AW,BW,CW		Triac	=BTA 26-...: snubberless di/dt AW: Igt/Ih<75/<100, BW: <50/<75, CW: <35/<50mA		18l	TO-3P Iso		-
BTA 40-....A	Tho	Triac	200...800V, 40A=(Tc=60°), Igt/Ih<150/<100mA		64l	(RD91)		(BTW 41/...)[3]
BTA 40-....B		Triac	=BTA 40-...A: Igt/Ih<80/<80mA		64l	(RD91)		(MAC 50A-...)[3]
BTA 41-....A	Tho	Triac	200...800V, 40A=(Tc=75°), Igt/Ih<150/<100mA		18l	TO-3P Iso		-
BTA 41-....B		Triac	=BTA 41-...A: Igt/Ih<100/<80mA		18l	TO-3P Iso		-
BTA 140/...	Phi	Triac	500...800V, 25A=(Tc=89°), Igt/Ih<70/<30mA		17j	TO-220		TXE 10..., MAC 223-..., MAC 223A-...
BTB								
BTB 04-....A	Tho	Triac	=BTA 04-...A:		17j	TO-220	TAG 232-600	17j T 2506..., T 2806..., TAG 220...
BTB 04-....D		Triac	=BTA 04-...D:		17j	TO-220	TAG 232-600	17j TXC 18H..., TIC 216..., TXC 18H...M
BTB 04-....S		Triac	=BTA 04-...S:		17j	TO-220	TAG 232-600	17j TXC 18G..., TAG 232..., TAG 221..., ++
BTB 04-....T		Triac	=BTA 04-...T:		17j	TO-220	TAG 232-600	17j TXC 18D..., TAG 233..., TAG 222..., ++
BTB 06-....A	Tho	Triac	=BTA 06-...A:		17j	TO-220		T 2506..., T 2806..., T 6006...
BTB 06-....B		Triac	=BTA 06-...B:		17j	TO-220		TXC 10K/L...M, TW7N..., MAC 222-..., ++
BTB 06-....C		Triac	=BTA 06-...C:		17j	TO-220		TXC 10K/L...M, TW7N..., MAC 222-..., ++
BTB 06-....D		Triac	=BTA 06-...D:		17j	TO-220		TIC 216..., TXC 18H...M
BTB 06-....GP		Triac	=BTA 06-...GP:		17j	TO-220		TXC 10K/L...M, TW7N..., MAC 222-..., ++
BTB 06-....S		Triac	=BTA 06-...S:		17j	TO-220		TXC 18G...M, TAG 221..., TAG 226...
BTB 06-....T		Triac	=BTA 06-...T:		17j	TO-220		TAG 222..., TXC 18D...M, TAG 227...
BTB 06-...AW,BW,CW		Triac	=BTA 06-...AW,BW,CW		17j	TO-220		-
BTB 06-...SW,TW		Triac	=BTA 06-...SW,TW:		17j	TO-220		-
BTB 08-....A	Tho	Triac	=BTA 08-...A:		17j	TO-220		T 2806..., T 6006...
BTB 08-....B		Triac	=BTA 08-...B:		17j	TO-220		MAC 222-..., TIC 226..., T 2802..., ++
BTB 08-....C		Triac	=BTA 08-...C:		17j	TO-220		MAC 222-..., TIC 226..., T 2802..., ++
BTB 08-....GP		Triac	=BTA 08-...GP:		17j	TO-220		TAG 224-..., MAC 222A-..., BT 137/..., ++
BTB 08-....S		Triac	=BTA 08-...S:		17j	TO-220		TAG 226..., MAC 228A-...
BTB 08-...AW,BW,CW		Triac	=BTA 08-...AW,BW,CW:		17j	TO-220		-
BTB 08-...SW,TW		Triac	=BTA 08-...SW,TW:		17j	TO-220		-
BTB 10-....B	Tho	Triac	=BTA 10-...B:		17j	TO-220		TW9N..., TXD 10K/L...M, TIC 236..., ++
BTB 10-....C		Triac	=BTA 10-...C:		17j	TO-220		TAG 250-..., TAG 251-..., TXD 10H...M, ++
BTB 10-...AW,BW,CW		Triac	=BTA 10-...AW,BW,CW:		17j	TO-220		-
BTB 12-....B	Tho	Triac	=BTA 12-...B:		17j	TO-220		TIC 236..., TW11N..., 2N6342...6345A, ++
BTB 12-....C		Triac	=BTA 12-...C:		17j	TO-220		TIC 236..., TW11N..., 2N6342...6345A, ++
BTB 12-...AW,BW,CW		Triac	=BTA 12-...AW,BW,CW:		17j	TO-220		-
BTB 13-....B	Tho	Triac	=BTA 13-...B:		17j	TO-220		TIC 236..., TW11N..., 2N6342...6345A, ++
BTB 15-....B	Tho	Triac	200...800V, 15A=(Tc=75°), Igt/Ih<75/<50mA		17j	TO-220		MAC 15-..., TIC 246..., T 6001..., ++
BTB 16-....B	Tho	Triac	=BTA 16-...B:		17j	TO-220		MAC 15-..., TIC 246..., T 6001..., ++
BTB 16-....C		Triac	=BTA 16-...C:		17j	TO-220		MAC 15-..., TIC 246..., T 6001..., ++
BTB 16-...AW,BW,CW		Triac	=BTA 16-...AW,BW,CW:		17j	TO-220		-
BTB 19-....B	Tho	Triac	200...700V, 19A=(Tc=75°), Igt/Ih<100/<50mA		17j	TO-220		TXE 10..., MAC 223-..., MAC 223A-...
BTB 20-...AW,BW,CW	Tho	Triac	=BTA 20-...AW,BW,CW:		17j	TO-220		-
BTB 24-....B		Triac	=BTB 19-...B: 25A(Tc=75°)		17j	TO-220		TXE 10..., MAC 223-..., MAC 223A-...
BTB 25-....A	Tho	Triac	=BTA 25-...A:		64j	(RD91)		(BTW 41/...)[4]
BTB 25-....B		Triac	=BTA 25-...B:		64j	(RD91)		(MAC 525-..., MAC 25-..., MAC 50-...)[4]
BTB 26-....A	Tho	Triac	=BTA 26-...A:		18j	TO-3P		-
BTB 26-....B		Triac	=BTA 26-...B:		18j	TO-3P		BTB 41-...
BTB 40-....A	Tho	Triac	=BTA 40-...A:		64j	(RD91)		(BTW 41/...)[4]
BTB 40-....B		Triac	=BTA 40-...B:		64j	(RD91)		(MAC 50-..., TAG 740-..., TAG 741-...)[4]
BTB 41-....A	Tho	Triac	=BTA 41-...A:		18j	TO-3P		-
BTB 41-....B		Triac	=BTA 41-...B:		18j	TO-3P		-
BTD								
BTD 4 L...N	Say	Diac	Ub=26...40V, Ib<0,05mA, Itsm=2A L=26...32V, M=29...37V, N=34...40V		31	DO-41		1N5761...62, D3202U,Y
BTD 0105	Tra	Triac	50V, 1A=(Tc=80°), Igt/Ih<25/<25mA		2v	TO-39		T 2306..., TAG 200-..., T 2303...
BTD 0110		Triac	=BTD 0105: 100V		2v	TO-39		T 2306..., TAG 200-..., T 2303...
BTD 0120		Triac	=BTD 0105: 200V		2v	TO-39		T 2306..., TAG 200-..., T 2303...
BTD 0140		Triac	=BTD 0105: 400V		2v	TO-39		T 2306..., TAG 200-..., T 2303...
BTD 0160		Triac	=BTD 0105: 600V		2v	TO-39		T 2306..., TAG 200-..., T 2303...

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BTD 0205-1	Tra	Triac	50V, 1,6A≈(Tc=80°), Igt/Ih=10/<10mA		2v	TO-39			TAG 201..., T 2302..., TAG 202-..., ++
BTD 0210-1		Triac	=BTD 0205-1: 100V		2v	TO-39			TAG 201..., T 2302..., TAG 202-..., ++
BTD 0220-1		Triac	=BTD 0205-1: 200V		2v	TO-39			TAG 201..., T 2302..., TAG 202-..., ++
BTD 0240-1		Triac	=BTD 0205-1: 400V		2v	TO-39			TAG 201..., T 2302..., TAG 202-..., ++
BTD 02...-2		Triac	=BTD 02...-1: Igt/Ih=6/<10mA		2v	TO-39			T 2301..., TAG 204-..., TAG 204A-...
BTD 02...-3		Triac	=BTD 02...-1: Igt/Ih=3/<10mA		2v	TO-39			TAG 206-..., TAG 207-...
BTD 0305	Tra	Triac	50V, 3A≈(Tc=80°), Igt/Ih<50/<50mA		2v	TO-39			-
BTD 0310		Triac	=BTD 0305: 100V		2v	TO-39			-
BTD 0320		Triac	=BTD 0305: 200V		2v	TO-39			-
BTD 0340		Triac	=BTD 0305: 400V		2v	TO-39			-
BTD 0360		Triac	=BTD 0305: 600V		2v	TO-39			-
BTD 03...-1		Triac	=BTD 03...: Igt/Ih<10/<15mA		2v	TO-39			TAG 202-..., TAG 203-..., TAG 209-...
BTD 03...-2		Triac	=BTD 03...: Igt/Ih<4/<10mA		2v	TO-39			TAG 204-..., TAG 205-...
BTD 03...-3		Triac	=BTD 03...: Igt/Ih<3/<5mA		2v	TO-39			TAG 206-..., TAG 207-...
BTD 0605	Tra	Triac	50V, 6A≈(Tc=80°), Igt/Ih<50/<50mA		2v	TO-39			-
BTD 0610		Triac	=BTD 0605: 100V		2v	TO-39			-
BTD 0620		Triac	=BTD 0605: 200V		2v	TO-39			-
BTD 0640		Triac	BTD 0605: 400V		2v	TO-39			-
BTD 0660		Triac	=BTD 0605: 600V		2v	TO-39			-
BTE 5 M	Say	Diac	Ub=29...37V, Ib<0,05mA, Itsm=2A		31	DO-35			1N5762, D3202Y
BTL									
BTL 0405	Tra	Triac	50V, 4A≈(Tc=80°), Igt/Ih<25/<25mA		17j	TO-220	TAG 232-600	17j	T 2506..., T 2806..., TAG 220-..., ++
BTL 0410		Triac	=BTL 0405: 100V		17j	TO-220	TAG 232-600	17j	T 2506..., T 2806..., TAG 220-..., ++
BTL 0420		Triac	=BTL 0405: 200V		17j	TO-220	TAG 232-600	17j	T 2506..., T 2806..., TAG 220-..., ++
BTL 0440		Triac	=BTL 0406: 400V		17j	TO-220	TAG 232-600	17j	T 2506..., T 2806..., TAG 220-..., ++
BTL 0460		Triac	=BTL 0405: 600V		17j	TO-220	TAG 232-600	17j	T 2506..., T 2806..., TAG 220-..., ++
BTL 0605	Tra	Triac	50V, 6A≈(Tc=80°), Igt/Ih<50/<50mA		17j	TO-220	(TAG 232-600)[7]	17j	TW7N..., MAC 222-..., TIC 226..., T 2802...
BTL 0610		Triac	=BTL 0605: 100V		17j	TO-220	(TAG 232-600)[7]	17j	TW7N..., MAC 222-..., TIC 226..., T 2802...
BTL 0620		Triac	=BTL 0605: 200V		17j	TO-220	(TAG 232-600)[7]	17j	TW7N..., MAC 222-..., TIC 226..., T 2802...
BTL 0640		Triac	=BTL 0605: 400V		17j	TO-220	(TAG 232-600)[7]	17j	TW7N..., MAC 222-..., TIC 226..., T 2802...
BTL 0660		Triac	=BTL 0605: 600V		17j	TO-220	(TAG 232-600)[7]	17j	TW7N..., MAC 222-..., TIC 226..., T 2802...
BTL 0805	Tra	Triac	50V, 8A≈(Tc=80°), Igt/Ih<50/<50mA		17j	TO-220			TIC 226..., T 2802..., TXD 10K/L..., ++
BTL 0810		Triac	=BTL 0805: 100V		17j	TO-220			TIC 226..., T 2802..., TXD 10K/L..., ++
BTL 0820		Triac	=BTL 0805: 200V		17j	TO-220			TIC 226..., T 2802..., TXD 10K/L..., ++
BTL 0840		Triac	=BTL 0805: 400V		17j	TO-220			TIC 226..., T 2802..., TXD 10K/L..., ++
BTL 0860		Triac	=BTL 0805: 600V		17j	TO-220			TIC 226..., T 2802..., TXD 10K/L..., ++
BTL 1005	Tra	Triac	50V, 10A≈(Tc=80°), Igt/Ih<100/<100mA		17j	TO-220			TW9N..., TXD 10K/L..., TIC 236..., ++
BTL 1010		Triac	=BTL 1005: 100V		17j	TO-220			TW9N..., TXD 10K/L..., TIC 236..., ++
BTL 1020		Triac	=BTL 1005: 200V		17j	TO-220			TW9N..., TXD 10K/L..., TIC 236..., ++
BTL 1040		Triac	=BTL 1005: 400V		17j	TO-220			TW9N..., TXD 10K/L..., TIC 236..., ++
BTL 1060		Triac	=BTL 1005: 600V		17j	TO-220			TW9N..., TXD 10K/L..., TIC 236..., ++
BTL 1605		Triac	50V, 16A≈(Tc=80°), Igt/Ih<100/<100mA		17j	TO-220			SC 151..., MAC 15-..., TIC 246..., ++
BTL 1610		Triac	=BTL 1605: 100V		17j	TO-220			SC 151..., MAC 15-..., TIC 246..., ++
BTL 1620		Triac	=BTL 1605: 200V		17j	TO-220			SC 151..., MAC 15-..., TIC 246..., ++
BTL 1640		Triac	=BTL 1605: 400V		17j	TO-220			SC 151..., MAC 15-..., TIC 246..., ++
BTL 1660		Triac	=BTL 1605: 600V		17j	TO-220			SC 151..., MAC 15-..., TIC 246..., ++
BTM									
BTM 0405...0460	Tra	Triac	=BTL 0405...0460:		17j	TO-220	TAG 232-600	17j	›BTL 0405...0460
BTM 0605...0660	Tra	Triac	=BTL 0605...0660:		17j	TO-220	›BTL 0605...		›BTL 0605...0660
BTM 1005...1060	Tra	Triac	=BTL 1005...1060:		17j	TO-220			›BTL 1005...1060
BTM 1605...1660	Tra	Triac	=BTL 1605...1660:		17j	TO-220			›BTL 1605...1660
BTR									
BTR 59/...R	Phi	GTO-Thy	800...1300V, 10A(Tc=85°C), 16,5A=, Igt<500mA, <1µs		18e	TO-3P			BTS 59/...R
BTR 0205	Tra	Triac	50V, 3A(Tc=75°), Igt/Ih<50/<25mA		22m	TO-66	TAG 232-600	17j	TAG 260-..., TAG 265-..., T 4700...
BTR 0210		Triac	=BTR 0205: 100V		22m	TO-66	TAG 232-600	17j	TAG 260-..., TAG 265-..., T 4700...
BTR 0220		Triac	=BTR 0205: 200V		22m	TO-66	TAG 232-600	17j	TAG 260-..., TAG 265-..., T 4700...
BTR 0240		Triac	=BTR 0205: 400V		22m	TO-66	TAG 232-600	17j	TAG 260-..., TAG 265-..., T 4700...
BTR 0260		Triac	=BTR 0205: 600V		22m	TO-66	TAG 232-600	17j	TAG 260-..., TAG 265-..., T 4700...
BTR 0305	Tra	Triac	50V, 6A(Tc=75°), Igt/Ih<50/<50mA		22m	TO-66	(TAG 232-600)[7]	17j	TAG 260-..., TAG 265-..., T 4700...
BTR 0310		Triac	=BTR 0305: 100V		22m	TO-66	(TAG 232-600)[7]	17j	TAG 260-..., TAG 265-..., T 4700...
BTR 0320		Triac	=BTR 0305: 200V		22m	TO-66	(TAG 232-600)[7]	17j	TAG 260-..., TAG 265-..., T 4700...
BTR 0340		Triac	=BTR 0305: 400V		22m	TO-66	(TAG 232-600)[7]	17j	TAG 260-..., TAG 265-..., T 4700...
BTR 0360		Triac	=BTR 0305: 600V		22m	TO-66	(TAG 232-600)[7]	17j	TAG 260-..., TAG 265-..., T 4700...
BTR 0405	Tra	Triac	50V, 10A(Tc=75°), Igt/Ih<100/<50mA		22m	TO-66			TAG 265-..., T 4700...
BTR 0410		Triac	=BTR 0405: 100V		22m	TO-66			TAG 265-..., T 4700...
BTR 0420		Triac	=BTR 0405: 200V		22m	TO-66			TAG 265-..., T 4700...
BTR 0440		Triac	=BTR 0405: 400V		22m	TO-66			TAG 265-..., T 4700...
BTR 0460		Triac	=BTR 0405: 600V		22m	TO-66			TAG 265-..., T 4700...
BTR 0505	Tra	Triac	50V, 15A, Igt/Ih<80/<50mA		22m	TO-66			T 4700...
BTR 0510		Triac	=BTR 0505: 100V		22m	TO-66			T 4700...
BTR 0520		Triac	=BTR 0505: 200V		22m	TO-66			T 4700...
BTR 0530		Triac	=BTR 0505: 300V		22m	TO-66			T 4700...
BTR 0540		Triac	=BTR 0505: 400V		22m	TO-66			T 4700...
BTR 0550		Triac	=BTR 0505: 500V		22m	TO-66			T 4700...
BTR 0560		Triac	=BTR 0505: 600V		22m	TO-66			T 4700...
BTR 0605...0660	Tra	Triac	=BTL 0605...0660:		22m	TO-66			TAG 260-..., TAG 265-..., T 4700...
BTR 1005...1060	Tra	Triac	=BTL 1005...1060:		22m	TO-66			TAG 265-..., T 4700...
BTR 1605...1660	Tra	Triac	=BTL 1605...1660:		22m	TO-66			T 4700...
BTS									
BTS 59/850R	Phi	GTO-Thy	850V, 15A(Tc=85°), Igt<300mA, toff<0,85µs		18e	TO-3P			-
BTS 59/1000R		GTO-Thy	=BTS 59/850R: 1000V		18e	TO-3P			-
BTS 59/1200R		GTO-Thy	=BTS 59/850R: 1200V		18e	TO-3P			-
BTS 100	Sie	MOS-P-FET-e	VFET, TEMPFET, 50/20V, 8A, 40W,<0,3Ω(5A), 80/125ns		17c	TO-220			-
BTS 110	Sie	MOS-N-FET-e	VFET,TEMPFET,100/20V, 10A, 40W, <0,2Ω(5A),65/125ns		17c	TO-220			-
BTS 114	Sie	MOS-N-FET-e	VFET, TEMPFET, 50/20V, 14A, 40W, on<0,1Ω(9A)		17c	TO-220			-
BTS 115	Sie	MOS-N-FET-e	VFET, TEMPFET, 50/10V, 12,5A, 40W, on<125mΩ(6A)		17c	TO-220			-
BTS 116	Sie	MOS-N-FET-e	VFET,TEMPFET, 50/20V, 14A, 40W, <0,1Ω(9A),75/150ns		≈30c	≈TO-251			-
BTS 120	Sie	MOS-N-FET-e	VFET, TEMPFET, 100/20V, 19A, 75W, on<0,1Ω(9A)		17c	TO-220			-
BTS 121 A	Sie	MOS-N-FET-e	VFET, TEMPFET, 100/20V, 22A, 75W, on<0,1Ω(9,5A)		17c	TO-220			-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BTS 129	Sie	MOS-N-FET-e	VFET, TEMPFET, 60/20V, 27A, 75W, on<0,05Ω(17A)		17c	TO-220			-
BTS 130	Sie	MOS-N-FET-e	VFET, TEMPFET, 50/20V, 27A, 75W, on<0,05Ω(17A)		17c	TO-220			-
BTS 131	Sie	MOS-N-FET-e	VFET, TEMPFET, 50/20V, 25A, 75W, on<0,06Ω(12A)		17c	TO-220			-
BTS 132	Sie	MOS-N-FET-e	VFET, TEMPFET, 60/20V, 24A, 75W, on<65mΩ(12A)		17c	TO-220			-
BTS 136	Sie	MOS-N-FET-e	VFET, TEMPFET, 50/20V, 27A, 75W, on<0,05Ω(17A)		≈30c	≈TO-251			-
BTS 140 A	Sie	MOS-N-FET-e	VFET, TEMPFET, 50/20V, 39A, 75W, on<28mΩ(25A)		17c	TO-220			-
BTS 240 A	Sie	MOS-N-FET-e	VFET, TEMPFET, 50/20V, 58A, 170W, on<18mΩ(47A)		18c	TO-3P			-
BTS 410	Sie	MOS-N-FET	VFET, PROFET, 50V, 75W, on<0,22Ω		17/5Pin	TO-220/5			-
BTS 412 A	Sie	MOS-N-FET	VFET, PROFET, 45V, 11A, 75W, on<0,4Ω		17/5Pin	TO-220/5			-
BTS 412 B	Sie	MOS-N-FET	VFET, PROFET, 56V, 14A, 75W, on<0,25Ω		17/5Pin	TO-220/5			-
BTS 413 A	Sie	MOS-N-FET	VFET, PROFET, 45V, 11A, 75W, on<0,4Ω		17/5Pin	TO-220/5			-
BTS 432	Sie	MOS-N-FET	VFET, PROFET, 50V, 125W, on<38mΩ		17/5Pin	TO-220/5			-
BTS 542	Sie	MOS-N-FET	VFET, PROFET, 50V, 170W, on<20mΩ		17/5Pin	TO-220/5			-
BTS 629	Sie	MOS-FET	Dimmer, 60V, 35W, on<0,2Ω		TO-220/7				-
BTS 630	Sie	MOS-FET	Dimmer, 60V, 60W, on<0,06Ω		TO-220/7				-
BTS 903	Sie	MOS-P-FET-e	VFET, TEMPFET, 200/20V, 3,6A, 50W, on<1,5Ω(2,3A)		17/5Pin	TO-220/5			-
BTS 950	Sie	MOS-N-FET-e	VFET, TEMPFET, 500/20V, 9A, 125W, <0,8Ω(6,5A)		TO-3P/5				-
BTV									
BTV 24/....R	Phi	50Hz-Thy	600...1400V, 45A(Tc=85°), 70A, Igt/Ih<100/<200mA		53b	TO-65			(T 35N..., T 45N...)[4]
BTV 34/...G	Phi	Triac	=BTW 34/...G		53b	TO-65			-
BTV 34/...H	Phi	Triac	=BTW 34/...H		53b	TO-65			-
BTV 58/....R	Phi	GTO-Thy	+600...+1000V, 10A, Igt<0,2mA, toff<0,75µs		17e	TO-220			-
BTV 59/...R	Phi	GTO-Thy	+600...+1000V, 15A(Tc=60°), Igt<300mA, toff=0,75µs		66b	TO-238			BTV 70/...R
BTV 59D/...R	Phi	GTO-Thy+Di	=BTV 59/...R: integr. Diode		66b	TO-238			BTV 70D/...R
BTV 60/...R	Phi	GTO-Thy	+850...+1200V, 25A(Tc=70°), Igt<500mA, toff=1,3µs		66b	TO-238			-
BTV 60D/...R	Phi	GTO-Thy+Di	=BTV 60/...R: integr. Diode		66b	TO-238			-
BTV 70/...R	Phi	GTO-Thy	+850...+1200V, 15A(Tc=60°), Igt<300mA, toff=0,85µs		66b	TO-238			-
BTV 70D/...R	Phi	GTO-Thy+Di	=BTV 70/...R: integr. Diode		66b	TO-238			-
BTV 159/...R	Phi	GTO-Thy	+850...+1200V, 15A, Igt<300mA		≈67	SOT-227A			-
BTV 160/...R	Phi	GTO-Thy	+850...+1200V, 25A, Igt<300mA		≈67	SOT-227A			-
BTW									
BTW 10/....	Tra	Triac	50...600V, 3A≈(Tc=75°), Igt/Ih<50/<25mA		22m	TO-66	TAG 232-600	17j	TXC01..., T 4706..., BS7-...A, MAC 216-...++
BTW 11/....	Tra	Triac	50...600V, 6A≈(Tc=75°), Igt/Ih<50/<50mA		22m	TO-66	TAG 232-600	17j	TXC 01..., TAG 262-..., TAG 265-..., ++
BTW 12/....	Tra	Triac	=BTW 11/...		29l	TO-203			BS 6-...B, TW 6N...H, BS 8-...B, TW 10N...H
BTW 13/....	Tra	Triac	=BTW 11/...		21l	≈TO-48			BS 6-...A, TW 6N...C, BS 8-...A, TW 8N...C++
BTW 14/....	Tra	Triac	50...600V, 10A≈(Tc=75°), Igt/Ih<100/<50mA		22m	TO-66			T 4706..., TAG 265-..., T 4700..., ++
BTW 15/....	Tra	Triac	=BTW 14/...		29l	TO-203			SC 246..., BS 10-...B, TW 10N...H, ++
BTW 16/....	Tra	Triac	=BTW 14/...		21l	≈TO-48			SC 245..., BS 10-...A, TW 10N...C, ++
BTW 17/....	Tra	Triac	=BTW 14/...		54l	≈TO-48Iso			SC 245..., BS 10-...A, TW 10N...C, ++
BTW 18/....	Tra	Triac	50...600V, 15A≈(Tc=75°), Igt/Ih<100/<50mA		29l	TO-203			SC 251..., SC 261..., 2N6157...6159, ++
BTW 19/....	Tra	Triac	=BTW 18/...		21l	≈TO-48			SC 250..., TXD 98..., TXE 99..., ++
BTW 20/....	Tra	Triac	50...600V, 25A(Tc=75°), Igt/Ih<100/<100mA		21l	≈TO-48			TXE 99..., SC 260..., T 6410..., ++
BTW 21/....	Tra	Triac	=BTW 20/...		29l	TO-203			SC 261..., T 6407..., T 6405..., ++
BTW 23/....(RM,RU)	Phi	50Hz-Thy	600...1600V, 90A(Tc=85°), 140A≈, Igt/Ih<150/<200mA		53b	TO-94			T 51 N...B, T 71 N...B, T 99 N...B, ++
BTW 24/....(RM,RU)	Phi	50Hz-Thy	600...1600V, 35A(Tc=85°), 55A≈, Igt/Ih<150/<200mA		53b	TO-103			T 35 N..., T 45 N...
BTW 26/....	Phi	Triac	150...600V, 14A(Tc=50°), Igt/Ih<35/<20mA		66	TO-238			MAC 525A-..., MAC 25A-..., TAG 725-..., ++
BTW 27/....R	Tho	50Hz-Thy	100...600V, 4,7A(Tc=75°), 10A≈, Igt/Ih<50/50mA		22a	TO-66	(TAG 626-600)[5]	17e	TAG 675-..., TAG 676-..., BStD 10..., ++
BTW 27 S,SA/....	Phi	F-Thy	+100...+600V, 7A≈(Tc=70°), Igt/Ih<50/25mA, <6µs		22a	TO-66	TD 3FP 800H[1]*	17f	(TAG 670S-..., T3S-..., TAG 675S-..., ++)
BTW 28(A)/....R	Tho	F-Thy	-150/+500...-300/+800V, 35A≈, Igt/Ih<150/45mA		21b	TO-48			BTW 63/..., CS 15,9-..., TAG 35S-...
BTW 30/....(RM,RU)	Phi,Tho	F-Thy	300...1200V, 12A(Tc=85°), 24A≈,Igt/Ih<0,2/0,2A,<6µs		21b	TO-48			BTW 31/...
BTW 30/....RS		F-Thy	=BTW 30/....(RM,RU): <15µS		21b	TO-48			BTW 31/...
BTW 31/....RM,RU,RW	Phi	F-Thy	300...1200V, 16A(85°), 31A≈, Igt/Ih<0,2/<0,2A,<12µs		21b	TO-48			-
BTW 32/....(RM,RU)	Phi	F-Thy	300...1200V, 25A(85°), 55A≈,Igt/Ih<0,15/<0,2A,<25µs		53b	TO-103			T 31F..., CSF 34-...
BTW 33/....(RM,RU)	Phi	F-Thy	300...1200V, 65A(85°),110A≈,Igt/Ih<0,15/<0,2A,<25µs		53b	TO-94			CS 38-..., CS 78-..., CS 79-..., T 71F...B
BTW 34/...(M,G,H,U)	Phi	Triac	600...1600V, 21A(Tc=85°), 55A≈, Igt/Ih<0,2/<0,2A		53l	TO-103			-
BTW 35	Phi	50Hz-Thy	500V, 15A≈, Igt<10mA, <50µs		21b	TO-64			-
BTW 36/....RM	Phi	50Hz-Thy	200...600V, 31A(Tc=65°C), Igt/Ih<60/<40mA						-
BTW 37(V)/....	Phi	Triac	400...1200V, 12A≈(Tc=85°), Igt/Ih<0,1/<0,1A		21l	TO-64			BTW 43/...
BTW 38/....R	Phi	50Hz-Thy	600...1200V, 10A(Tc=85°), 16A≈, Igt/Ih<50/<75mA		21b	TO-48			BTW 42/..., BStC03..., CS 5-..., BStD03
BTW 39/....	Tho	50Hz-Thy	50...1200V, 16A(Tc=75°), 25A≈, Igt/Ih<80/20mA		21b	TO-48			BTW45/..., BTW 47/..., CS13-..., T15.1N...++
BTW 40/....R	Phi	50Hz-Thy	200...800V, 20A(Tc=85°), 32A≈, Igt/Ih<75/<75mA		21b	TO-48			BTW 47/...,CS 13-...,T15.1N...,TAG 16N...,++
BTW 41/....(G,H)	Phi	Triac	400...800V, 40A≈(Tc=60°), Igt/Ih<150/50mA			SOT-80			-
BTW 42/....R	Phi	50Hz-Thy	600...1200V, 10(Tc=85°), 16A≈, Igt/Ih<50/<75mA		21b	TO-64			-
BTW 43/....(G,H)	Phi	Triac	600...1200V, 9,5A(Tc=35°), 15A≈, Igt/Ih<200/<100mA		21l	TO-64			-
BTW 44/....(M,U)	Phi	Triac	100...600V, 23A(Tc=85°), Igt/Ih<0,2/<0,2A		53l	TO-103			-
BTW 45/....R	Phi	50Hz-Thy	200...1200V, 16A(Tc=85°), 25A≈, Igt/Ih<75/<75mA		21b	TO-48			BTW 47/..., CS 13-..., T 15.1N..., CS16...++
BTW 46/....R	Phi	50Hz-Thy	200...600V, 25A(Tc=65°), Igt/Ih<60/<40mA						-
BTW 47/....(RM,RU)	Phi	50Hz-Thy	200...1600V, 14A(Tc=85°), 25A≈, Igt/Ih<100/<200mA		21b	TO-48			BTW 39/..., BTW 47/...,CS 13...,TAG 16N...++
BTW 48/....[Tho]	Tho	50Hz-Thy	200...1200V, 50A≈(Tc=85°), Igt/Ih<60/30mA, 50µs		21b	TO-48			CS 23-...
BTW 48/....[Phi]	Phi	Triac	›≈BTX 94/...		21l	TO-48			›BTX 94/...
BTW 49/....	Tho	F-Thy	50...800V, 15A≈(Tc=75°), Igt/Ih<200/75mA, <20µs		21b	TO-48			BTW 30/..., BTW 31/..., CS 15,9-..., ++
BTW 50/....	Tho	50Hz-Thy	100...1200V, 63A≈(105°), Igt/Ih<150/50mA		21b	TO-65			-
BTW 52	Itt	Thy	60V, 8A(Tc=65°), Igt/Ih<20/25mA, 17µs		22a	TO-66	17127[5]	17e	BStC0506, TAG 671-100, TAG 676-100, ++
BTW 53	Itt	Thy	=BTW 52: 120V		22a	TO-66	17127[5]	17e	BStC0513, TAG 671-200, TAG 676-200, ++
BTW 54	Itt	Thy	=BTW 52: 240V		22a	TO-66	17127[5]	17e	BStC0526, TAG 671-300, TAG 676-300, ++
BTW 55	Itt	Thy	=BTW 52: 480V		22a	TO-66	17127[5]	17e	BStC0533, TAG 671-500, TAG 676-500, ++
BTW 56	Itt	Thy	=BTW 52: 600V		22a	TO-66	17127[5]	17e	BStC0540, TAG 671-600, TAG 676-600, ++
BTW 58/....	Phi,Sie	GTO-Thy	+1000...+1500V, 7,5A≈, Igt<200mA, toff<0,75µs		17e	TO-220			-
BTW 59/....R	Phi	GTO-Thy	+1300...+1500V, 12A, Igt<250mA, tf<300ns		66	TO-238			-
BTW 62/....RK	Phi	F-Thy	600...1000V, 18A(85°), 28A≈, Igt/Ih<0,25/<0,4A,<4µs		66b	TO-238			-
BTW 62/....RN		F-Thy	=BTW 62/...RK: <9µs		66b	TO-238			-
BTW 62D/....		F-Thy+Di	=BTW 62/...RK: integr. Diode		66b	TO-238			-
BTW 63/....RK	Phi	F-Thy	600...800V, 25A(Tc=75°), Igt/Ih<0,25/<0,4A, 4µs		21b	TO-48			BTW 28/..., CS 15,9-..., TAG 35 S-...
BTW 63/....RN		F-Thy	=BTW 63/...RK: 6µs		21b	TO-48			BTW 28/..., CS 15,9-..., TAG 35 S-...
BTW 63/....RP		F-Thy	=BTW 63/...RK: 8µs		21b	TO-48			BTW 28/..., CS 15,9-..., TAG 35 S-...
BTW 66/....	Tho	50Hz-Thy	200...1200V, 25A≈(Tc=65°), Igt/Ih<50/<20mA		64b	(RD91)			BTW 67/...
BTW 66/....N		50Hz-Thy	=BTW 66/...:		64e	(RD91)			BTW 67/...N
BTW 67/....	Tho	50Hz-Thy	200...1200V, 40A≈(Tc=65°), Igt/Ih<80/<20mA		64b	(RD91)			-
BTW 67/....N		50Hz-Thy	=BTW 67/...:		64e	(RD91)			-
BTW 68/...	Tho	50Hz-Thy	200...1200V, 25A≈(Tc=110°), Igt/Ih<50/<75mA		18b	TO-3P Iso			BTW 69/...
BTW 68/...N		50Hz-Thy	=BTW 68/...:		18e	TO-3P			BTW 69/...N

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
BTW 69/...	Tho	50Hz-Thy	200...1200V, 40A=, Igt/Ih<80/<150mA		18b	TO-3P Iso		-
BTW 69/...N		50Hz-Thy	=BTW 69/...:		18e	TO-3P		-
BTW 92/...(R,RM,RU)	Phi	50Hz-Thy	200...1600V, 20A(Tc=85°), 31A=, Igt/Ih<100/<200mA		21b	TO-48		CS 16-..., CS 23-...
BTX								
BTX 12/....R	Phi	50Hz-Thy	100...700V, 20A, Igt/Ih<50/<40mA		53b	=TO-94		BTX 13/...R, CS 42-..., CS 50-...
BTX 13/....R	Phi	50Hz-Thy	100...700V, 22A(Tc=85°), 48A=, Igt/Ih<50/40mA, 6µs		53b	=TO-94		CS 42-..., CS 50-...
BTX 18/....	Phi	50Hz-Thy	100...500V, 1A(Tc=85°), 1.6A=, Igt/Ih<5/5mA, 35µs		2a	TO-5		BTX 30/..., T1N..., S 2600..., TAG 612...++
BTX 20	Phi	50Hz-Thy	200V, 78A(Tc=70°C), Igt/Ih<100/<100mA		53a	TO-49		-
BTX 21	Phi	50Hz-Thy	=BTX 20: 300V		53a	TO-49		-
BTX 22	Phi	50Hz-Thy	=BTX 20: 400V		53a	TO-49		-
BTX 23	Phi	50Hz-Thy	=BTX 20: 500V		53a	TO-49		-
BTX 24	Phi	50Hz-Thy	=BTX 20: 600V		53a	TO-49		-
BTX 25	Phi	50Hz-Thy	=BTX 20: 700V		53a	TO-49		-
BTX 26	Phi	50Hz-Thy	=BTX 20: 800V		53a	TO-49		-
BTX 29/....R	Phi	50Hz-Thy	200...1800V, 78A(Tc=110°C), Igt/Ih<100/<100mA		53a	=TO-94		CS 70-...
BTX 30/....	Tag	50Hz-Thy	50...600V, 1A(Tc=85°), 1.6A=, Igt/Ih<10/<25mA		2a	TO-39		T1N..., S2600..., TAG612-..., TAG613-...,++
BTX 31/....R	Tag	50Hz-Thy	50...1000V, 7A(Tc=95°C), 4.4A=, Igt/Ih<15/<15mA		21b	TO-48		T 10N...C
BTX 31S/....R		F-Thy	=BTX 31/...R: <12µs		21b	TO-48		TAG 15S-..., T 12F...
BTX 32/....R	Tag	50Hz-Thy	50...1000V, 10A(Tc=125°C), 6.3A=, Igt/Ih<25/<25mA		21b	TO-48		T 10N...C, T 12N..., 2N5204...5207, ++
BTX 32/....S		F-Thy	=BTX 32/...R: <12µs		21b	TO-48		TAG 15S..., T 12F...
BTX 33/....R	Phi	50Hz-Thy	50...1000V, 20A(Tc=125°C), 12.6A=, Igt/Ih<50/<50mA		21b	TO-48		TAG15-..., TAG14N..., BTW39/..., CS13...,++
BTX 33/....S		F-Thy	=BTX 33/...R: <12µs		21b	TO-48		T 12F-...
BTX 35/....R	Phi	50Hz-Thy	500...800V, 8.2A(Tc=85°C), 25A=,Igt/Ih<60/10mA,15µs		21b	TO-48		TAG 14N-..., BTW 39/..., BStE41..., ++
BTX 36/....R	Phi	50Hz-Thy	500...800V, 11A(Tc=85°C), 25A=, Igt/Ih<40/10mA,20µs		21b	TO-48		2N681...692, T 12N..., 2N5204...5207,++
BTX 37/....R	Phi	50Hz-Thy	500...800V, 32A(Tc=85°C), Igt/Ih<80/10mA, 20µs		53b	TO-94		CS 42-..., CS 50-..., CS 70-...
BTX 38/....R	Phi	50Hz-Thy	500...800V, 62A(Tc=85°C), 110A=,Igt/Ih<70/10mA,20µs		53b	TO-94		CS 42-..., CS 50-..., CS 70-...
BTX 41/....R	Phi	50Hz-Thy	200...1800V, 175A(Tc=85°), 315A=, Igt/Ih<300/<300mA		53b	TO-108		BStN 35/..., BStP 36/..., BStP 35/...
BTX 44/....R	Phi	50Hz-Thy	200...1800V, 55A=, Igt/Ih<100/<100mA		53b	=TO-94		CS 50-..., CS 70-...
BTX 45/....R	Phi	50Hz-Thy	200...1800V, 110A=(110°), Igt/Ih<100/<100mA		53b	=TO-94		CS 50-..., CS 70-...
BTX 46/....R	Phi	50Hz-Thy	200...1800V, 150A(Tc=85°), 235A=, Igt/Ih<300/<300mA		53b	TO-108		BStN 35/..., BStP 36/..., BStP 35/...
BTX 47/....R	Phi	50Hz-Thy	1000...1400V, 11A(Tc=85°), Igt/Ih<65/10mA, 50µs		21b	TO-48		BTW47/..., TAG16N..., BTW92/..., CS16-...,++
BTX 48/....R	Phi	50Hz-Thy	1000...1400V, 16A(Tc=85°), Igt/Ih<65/10mA, 50µs		21b	TO-48		BTW47/..., TAG16N..., BTW92/..., CS16-...,++
BTX 49/....R	Phi	50Hz-Thy	600...1400V, 60A(Tc=85°), Igt<100mA, 50µs		53b	TO-94		CS 42-..., CS 50-..., CS 70-...
BTX 50/....R	Phi	50Hz-Thy	600...1400V, 70A(Tc=85°), 110A=, Igt/Ih<100/<150mA		53b	TO-108		CS 42-..., CS 50-..., CS 70-...
BTX 51/....R	Phi	50Hz-Thy	500...800V, 70A, Igt/Ih<70/10mA, 20µs		53a	TO-49		-
BTX 52	Sgs	50Hz-Thy	100V, 8A(Tc=65°C), Igt/Ih<0.2/<2.5mA		23a	TO-3		-
BTX 53	Sgs	50Hz-Thy	=BTX 52: 200V		23a	TO-3		-
BTX 54	Sgs	50Hz-Thy	=BTX 52: 300V		23a	TO-3		-
BTX 55	Sgs	50Hz-Thy	=BTX 52: 400V		23a	TO-3		-
BTX 57	Sgs	50Hz-Thy	100V, 8A(Tc=85°C), Igt/Ih<15/<25mA		23a	TO-3		-
BTX 58	Sgs	50Hz-Thy	=BTX 57: 200V		23a	TO-3		-
BTX 59	Sgs	50Hz-Thy	=BTX 57: 300V		23a	TO-3		-
BTX 60	Sgs	50Hz-Thy	=BTX 57: 400V		23a	TO-3		-
BTX 64/....R	Phi	F-Thy	100...600V, 8,5A(Tc=85°C), 16A=,Igt/Ih<65/10mA,10µs		21b	TO-48		C 234-..., MCR 1718-..., TAG 12F..., ++
BTX 65/....R	Phi	F-Thy	100...600V, 12A(Tc=85°C), Igt/Ih<65/10mA, 10µs		21b	TO-48		C 234-..., MCR 1718-..., TAG 12F..., ++
BTX 66/....R	Phi	F-Thy	100...600V, 32A(Tc=85°C), Igt/Ih<80/10mA, 15µs		53b	TO-94		BStH 37..., BStH 34..., BStL 37..., ++
BTX 67/....R	Phi	F-Thy	100...600V, 62A(Tc=85°C), Igt/Ih<80/10mA, 15µs		53b	TO-94		BStL 34..., BStH 34..., BStL 37..., ++
BTX 68/....R	Phi	50Hz-Thy	500...1000V, 6,4A(Tc=85°C), Igt/Ih<30/10mA, 20µs		21b	TO-64		BStC 03..., BStD 03..., CS 5-..., CS 8-...
BTX 70/....R	Tag	50Hz-Thy	50...1000V, 15A=, Igt/Ih<50/<50mA, 25µs		21b	TO-48		TAG9N..., TAG15-..., BTW39/..., BTW45/...
BTX 70/....S		F-Thy	=BTX 70/...R: <12µs		21b	TO-48		TAG 15S..., T 12F...
BTX 71/....R	Tag	50Hz-Thy	50...1000V, 7A, 4,4A=, Igt/Ih<15/<15mA		21b	TO-48		T 10N...C, T 12N...
BTX 71/....S		F-Thy	=BTX 71/...: <12µs		21b	TO-48		TAG 15S..., T 12F...
BTX 72/....R	Tag	50Hz-Thy	50...1000V, 10A(Tc=95°C),6.3A=,Igt/Ih<25/<25mA,20µs		21b	TO-48		T 10N...C, T 12N...
BTX 72/....S		F-Thy	=BTX 72/...: <12µs		21b	TO-48		T 12F..., TAG 15S...
BTX 73/....(R,A,B)	Tag	50Hz-Thy	50...1000V, 25A(Tc=60°C), 16A=,Igt/Ih<50/<50mA,20µs		21b	TO-48		T 17N..., BTW 48/..., CS 23-...
BTX 73/....S		F-Thy	=BTX 73/...: <12µs		21b	TO-48		T 12F...
BTX 74/....R	Tag	50Hz-Thy	50...1000V, 15A=, Igt/Ih<50/<50mA, 20µs		21b	TO-48		TAG 9N..., TAG 15-..., BTW 39/..., ++
BTX 74/....S		F-Thy	50...1000V, 15A, Igt/Ih<50/<50mA <12µs		21b			TAG 15S..., T 12F...
BTX 75/....R	Phi	50Hz-Thy	100...400V, 8,5A(Tc=110°C),16A=,Igt/Ih<65/10mA,25µs		21b	TO-48		TAG 9N..., 2N1842...1850, TAG 15-..., ++
BTX 76/....R	Phi	50Hz-Thy	100...400V, 12A(Tc=110°C), 16A=,Igt/Ih<40/10mA,25µs		21b	TO-48		MCR 3918-..., 2N5168...5171, T 12N..., ++
BTX 81/....R(RM,RU)	Phi	50Hz-Thy	100...800V, 20A(Tc=85°C), Igt/Ih<80/100mA		21b	TO-48		BTW 40/..., BStE41...M, T 17N..., CS16...,++
BTX 82/....R(RM,RU)	Phi	50Hz-Thy	100...800V, 26A(Tc=85°C), Igt/Ih<80/100mA		21b	TO-48		BTW 48/..., CS 23-...
BTX 92/....R	Phi	50Hz-Thy	600.1600V, 16A(Tc=85°C), Igt/Ih<150/<200mA		21b	TO-48		BTW 47/..., CS 23-..., BTW 92/...
BTX 94/....(H,J)	Phi	Triac	100...1200V, 25A=(Tc=85°), Igt<200mA		21l	TO-48		-
BTX 95/....R	Phi,Tho	50Hz-Thy	500...800V, 10A(Tc=60°C), 15A=, Igt/Ih<50/30mA		21b	TO-64		TAG 15-..., BTW 39/..., T 15.1N..., ++
BTX 0605	Tra	Triac	50V, 6A=(Tc=80°C), Igt/Ih<50/<50mA, =BTL 0605...		54l	=TO-48Iso		SC 245A3, T 4120F, T 4121F, SC 250A3, ++
BTX 0610		Triac	=BTX 0605: 100V		54l	=TO-48Iso		SC 245B3, T 4120E, T 4121E, SC 250B3, ++
BTX 0620		Triac	=BTX 0605: 200V		54l	=TO-48Iso		SC 245A3, T 4120E, T 4221E, SC 250A3, ++
BTX 0640		Triac	=BTX 0605: 400V		54l	=TO-48Iso		SC 245D3, T 4120E, T 4121E, SC 250D3, ++
BTX 0660		Triac	=BTX 0605: 600V		54l	=TO-48Iso		SC 245M3, T 4120M, T 4121M, SC 250M3, ++
BTX 1005	Tra	Triac	50V, 10A=(Tc=80°), Igt/Ih<100/<100mA, =BTL 1005...		54l	=TO-48Iso		SC 245B3, T 4120F, T 4121F, SC 250B3, ++
BTX 1010		Triac	=BTX 1005: 100V		54l	=TO-48Iso		SC 245B3, T 4120E, T 4121E, SC 250B3, ++
BTX 1020		Triac	=BTX 1005: 200V		54l	=TO-48Iso		SC 245B3, T 4120E, T 4121E, SC 250B3, ++
BTX 1040		Triac	=BTX 1005: 400V		54l	=TO-48Iso		SC 245D3, T 4120E, T 4121E, SC 250D3, ++
BTX 1060		Triac	=BTX 1005: 600V		54l	=TO-48Iso		SC 245M3, T 4120M, T 4121M, SC 250M3, ++
BTX 1605	Tra	Triac	50V, 16A=(Tc=80°), Igt/Ih<100/<100mA, =BTL 1605...		54l	=TO-48Iso		SC 260B3, T 6421F, 2N6163...6165
BTX 1610		Triac	=BTX 1605: 100V		54l	=TO-48Iso		SC 260B3, T 6421B, 2N6163...6165
BTX 1620		Triac	=BTX 1605: 200V		54l	=TO-48Iso		SC 260B3, T 6421B, 2N6163...6165
BTX 1640		Triac	=BTX 1605: 400V		54l	=TO-48Iso		SC 260D3, T 6421D, 2N6164...6165
BTX 1660		Triac	=BTX 1605: 600V		54l	=TO-48Iso		SC 260M3, T 6421M, 2N6165
BTX 2505	Tra	Triac	50V, 25A=(Tc=80°), Igt/Ih<100/<100mA, =BTL 2505...		54l	=TO-48Iso		SC 260B3, T 6421F, 2N6163...6165
BTX 2510		Triac	=BTX 2505: 100V		54l	=TO-48Iso		SC 260B3, T 6421B, 2N6163...6165
BTX 2520		Triac	=BTX 2505: 200V		54l	=TO-48Iso		SC 260B3, T 6421B, 2N6163...6165
BTX 2540		Triac	=BTX 2505: 400V		54l	=TO-48Iso		SC 260D3, T 6421D, 2N6164...6165
BTX 2560		Triac	=BTX 2505: 600V		54l	=TO-48Iso		SC 260M3, T 6421M, 2N6165
BTY								
BTY 10	Aeg	50Hz-Thy	50V, 200A(Tc=125°C), Igt/Ih<200/<200mA, 40µs					-
BTY 11	Aeg	50Hz-Thy	=BTY 10: 100V					-
BTY 13	Aeg	50Hz-Thy	=BTY 10: 400V					-
BTY 15	Aeg	50Hz-Thy	=BTY 10: 500V					-
BTY 16	Aeg	50Hz-Thy	=BTY 10: 600V					-

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
BTY 20	Aeg	50Hz-Thy	50V, 90A(Tc=125°C), Igt/Ih<80/<100mA, 20µs		76b			T 99N400E, T 159N400E
BTY 21	Aeg	50Hz-Thy	=BTY 20: 100V		76b			T 99N400E, T 159N400E
BTY 22	Aeg	50Hz-Thy	=BTY 20: 200V		76b			T 99N400E, T 159N400E
BTY 23	Aeg	50Hz-Thy	=BTY 20: 400V		76b			T 99N400E, T 159N400E
BTY 24	Aeg	50Hz-Thy	=BTY 20: 500V		76b			T 99N600E, T 159N600E
BTY 25	Aeg	50Hz-Thy	=BTY 20: 600V		76b			T 99N600E, T 159N600E
BTY 28	Phi	50Hz-Thy	100V, 6A(Tc=60°C), Igt/Ih<15/<4mA, 19µs		21b	TO-64		T 6N100C, T 8N100C, BStD4126, T 10N100C
BTY 29	Phi	50Hz-Thy	=BTY 28: 150V		21b	TO-64		T 6N200C, T 8N200C, BStD4126, T 10N200C
BTY 30	Phi	50Hz-Thy	=BTY 28: 250V		21b	TO-64		T 6N300C, T 8N300C, BStD4126, T 10N300C
BTY 31	Phi	50Hz-Thy	=BTY 28: 300V		21b	TO-64		T 6N300C, T 8N300C, BStD4126, T 10N300C
BTY 34/....R	Phi	50Hz-Thy	100...400V, 6,4A(Tc=110°C), Igt<30mA, 20µs		21b	TO-48		2N5168...5171, MCR 3918-..., 2N681...692
BTY 34	Phi	50Hz-Thy	100V, 6A(Tc=60°C), Igt/Ih<15/<2mA, 14µs		21b	TO-64		T 6N100C, T 8N100C, BStD4126, T 10N100C
BTY 35	Phi	50Hz-Thy	=BTY 34: 150V, 16µs		21b	TO-64		T 6N200C, T 8N200C, BStD4126, T 10N200C
BTY 36	Phi	50Hz-Thy	=BTY 34: 200V, 18µs		21b	TO-64		T 6N200C, T 8N200C, BStD4126, T 10N200C
BTY 37	Phi	50Hz-Thy	=BTY 34: 250V, 20µs		21b	TO-64		T 6N300C, T 8N300C, BStD4126, T 10N300C
BTY 38	Phi	50Hz-Thy	=BTY 34: 300V, 22µs		21b	TO-64		T 6N300C, T 8N300C, BStD4126, T 10N300C
BTY 39	Phi	50Hz-Thy	=BTY 34: 400V, 24µs		21b	TO-64		T 6N400C, T 8N400C, BStD4126, T 10N400C
BTY 41	Phi	50Hz-Thy	50V, 9,6A(Tc=60°C), Igt/Ih<80/<20mA, 8,2µs		21b	TO-48		2N1843...1850, TAG 9N400, TAG 15-100
BTY 43	Phi	50Hz-Thy	=BTY 41: 150V, 7,5µs		21b	TO-48		2N1845...1850, TAG 9N400, TAG 15-200
BTY 44	Phi	50Hz-Thy	=BTY 41: 200V, 7,5µs		21b	TO-48		2N1846...1850, TAG 9N400, TAG 15-200
BTY 46	Phi	50Hz-Thy	=BTY 41: 300V, 7µs		21b	TO-48		2N1848...1850, TAG 9N400, TAG 15-300
BTY 47	Phi	50Hz-Thy	=BTY 41: 400V, 7µs		21b	TO-48		2N1850, TAG 9N400, TAG 15-400
BTY 50	Phi	50Hz-Thy	50V, 16A(Tc=60°C), Igt/Ih<40/<10mA, 8µs		21b	TO-48		2N682...692, T 12N100, C 228A, C 35A, ++
BTY 51	Phi	50Hz-Thy	=BTY 50: 100V, 8µs		21b	TO-48		2N683...692, T 12N100, C 228A, C 35A, ++
BTY 52	Phi	50Hz-Thy	=BTY 50: 150V, 7,2µs		21b	TO-48		2N684...692, T 12N200, C 228B, C 35B, ++
BTY 53	Phi	50Hz-Thy	=BTY 50: 250V, 6,6µs		21b	TO-48		2N686...692, T 12N300, C 228C, C 35C, ++
BTY 54	Phi	50Hz-Thy	=BTY 50: 300V, 6,6µs		21b	TO-48		2N687...692, T 12N300, C 228C, C 35C, ++
BTY 57	Phi	50Hz-Thy	50V, 16A(Tc=60°C), Igt/Ih<40/<10mA, 8µs		21b	TO-48		2N682...692, T 12N100, C 228A, C 35A, ++
BTY 58	Phi	50Hz-Thy	=BTY 57: 100V, 8µs		21b	TO-48		2N683...692, T 12N100, C 228A, C 35A, ++
BTY 59	Phi	50Hz-Thy	=BTY 57: 150V, 7,2µs		21b	TO-48		2N684...692, T 12N200, C 228B, C 35B, ++
BTY 60	Phi	50Hz-Thy	=BTY 57: 200V, 7,2µs		21b	TO-48		2N685...692, T 12N200, C 228B, C 35B, ++
BTY 61	Phi	50Hz-Thy	=BTY 57: 250V, 6,6µs		21b	TO-48		2N686...692, T 12N300, C 228C, C 35C, ++
BTY 62	Phi	50Hz-Thy	=BTY 57: 300V, 6,6µs		21b	TO-48		2N687...692, T 12N300, C 228C, C 35C, ++
BTY 64	Phi	50Hz-Thy	50V, 110A(Tc=60°C), Igt/Ih<70/<20mA		21b	TO-64		-
BTY 65	Phi	50Hz-Thy	=BTY 64: 100V		21b	TO-64		-
BTY 66	Phi	50Hz-Thy	=BTY 64: 150V		21b	TO-64		-
BTY 67	Phi	50Hz-Thy	=BTY 64: 200V		21b	TO-64		-
BTY 68	Phi	50Hz-Thy	=BTY 64: 250V		21b	TO-64		-
BTY 69	Phi	50Hz-Thy	=BTY 64: 300V		21b	TO-64		-
BTY 70	Phi	50Hz-Thy	=BTY 64: 400V		21b	TO-64		-
BTY 79/....R	Phi	50Hz-Thy	100...1000V, 10A(Tc=85°C), 16A~, Igt/Ih<30/<75mA		21b	TO-64		BTW 42/..., BStC03..., CS 5-..., BStD03...
BTY 79/....R/05	Phi	50Hz-Thy	=		21b	TO-64		BTW 42/..., BStC03..., CS 5-..., BStD03...
BTY 79A/05	Itt	50Hz-Thy	50V, 10A(Tc=65°C), Igt/Ih<20/<25mA, 17µs		21b	TO-64		BStD4126, S 6210A, T 10N100C
BTY 79A/10		50Hz-Thy	=BTY 79A/05: 100V		21b	TO-64		BStD4126, S 6210A, T 10N100C
BTY 79A/20		50Hz-Thy	=BTY 79A/05: 200V		21b	TO-64		BStD4126, S 6210B, T 10N200C
BTY 79A/30		50Hz-Thy	=BTY 79A/05: 300V		21b	TO-64		BStD4126, S 6210D, T 10N300C
BTY 79A/40		50Hz-Thy	=BTY 79A/05: 400V		21b	TO-64		BStD4126, S 6210D, T 10N400C
BTY 79A/50		50Hz-Thy	=BTY 79A/05: 500V		21b	TO-64		BStD4133, S 6210M, T 10N500C
BTY 80	Phi	50Hz-Thy	=BTY 79/200R		21b	TO-64		›BTY 79/...R
BTY 81	Phi	50Hz-Thy	=BTY 79/400R		21b	TO-64		›BTY 79/...R
BTY 84	Phi	50Hz-Thy	=BTY 79/100R		21b	TO-64		›BTY 79/...R
BTY 85	Phi	50Hz-Thy	=BTY 79/200R		21b	TO-64		›BTY 79/...R
BTY 86	Phi	50Hz-Thy	=BTY 79/300R		21b	TO-64		›BTY 79/...R
BTY 87/....R(RU,RM)	Phi	50Hz-Thy	100...800V, 10A(Tc=85°C), 25A~, Igt/Ih<65/10mA,15µs		21b	TO-48		TAG15-..., BTW39/..., CS13-..., TAG16N...,++
BTY 88	Phi	50Hz-Thy	=BTY 91/100R		21b	TO-48		›BTY 91/...R
BTY 89	Phi	50Hz-Thy	=BTY 91/200R		21b	TO-48		›BTY 91/...R
BTY 90	Phi	50Hz-Thy	=BTY 91/300R		21b	TO-48		›BTY 91/...R
BTY 91/....R(RU,RM)	Phi	50Hz-Thy	100...1200V, 14A(Tc=85°C), 25A~, Igt/Ih<40/25mA		21b	TO-48		T 12N..., 2N5204...5207
BTY 92	Phi	50Hz-Thy	=BTY 95/100R		53b	TO-94		›BTY 95/...R
BTY 93	Phi	50Hz-Thy	=BTY 95/200R		53b	TO-94		›BTY 95/...R
BTY 94	Phi	50Hz-Thy	=BTY 95/300R		53b	TO-94		›BTY 95/...R
BTY 95/....R	Phi	50Hz-Thy	100...800V, 32A(Tc=85°C), 110A~,Igt/Ih<80/10mA,20µs		53b	TO-94		CS 42-..., CS 50-..., CS 70-...
BTY 96	Phi	50Hz-Thy	=BTY 99/100R		53b	TO-94		›BTY 99/...R
BTY 97	Phi	50Hz-Thy	=BTY 99/200R		53b	TO-94		›BTY 99/...R
BTY 98	Phi	50Hz-Thy	=BTY 99/300R		53b	TO-94		›BTY 99/...R
BTY 99/....R	Phi	50Hz-Thy	100...800V, 62A(Tc=85°C), 110A~,Igt/Ih<70/10mA,20µs		53b	TO-94		CS 70-...
BTZ								
BTZ 10	Aeg	50Hz-Thy	50V, 24A(Tc=125°C), Igt/Ih<50/<30mA, 20µs		76			-
BTZ 11	Aeg	50Hz-Thy	=BTZ 10: 100V		76			-
BTZ 12	Aeg	50Hz-Thy	=BTZ 10: 200V		76			-
BTZ 13	Aeg	50Hz-Thy	=BTZ 10: 400V		76			-
BTZ 15	Aeg	50Hz-Thy	=BTZ 10: 500V		76			-
BTZ 16	Aeg	50Hz-Thy	=BTZ 10: 600V		76			-
BTZ 18	Aeg	50Hz-Thy	200V, 6A(Tc=60°C), Igt/Ih<15/4mA, 23µs		21b	TO-64		T 6N200C, T 8N200C, BStD4126
BTZ 19	Aeg	50Hz-Thy	=BTZ 18: 400V		21b	TO-64		T 6N400C, T 8N400C, BStD4126
BTZ 21	Aeg	50Hz-Thy	400V, 16A(Tc=60°C), Igt/Ih<40/10mA, 6,6µs		21b	TO-48		2N688...692, T 12N400, C 35D, MCR 64-6
BTZ 35	Aeg	50Hz-Thy	50V, 3,5A, Igt/Ih<40/10mA		21b	TO-48		2N1843...1850, TAG 9N400, TAG 15-100, ++
BTZ 36	Aeg	50Hz-Thy	=BTZ 35: 100V		21b	TO-48		2N1844...1850, TAG 9N400, TAG 15-100, ++
BTZ 37	Aeg	50Hz-Thy	=BTZ 35: 200V		21b	TO-48		2N1846...1850, TAG 9N400, TAG 15-200, ++
BTZ 38	Aeg	50Hz-Thy	=BTZ 35: 350V		21b	TO-48		2N1850, TAG 9N400, TAG 15-400,TAG 16N400
BTZ 39	Aeg	50Hz-Thy	=BTZ 35: 450V		21b	TO-48		2N1850, TAG 9N600, TAG 15-500,TAG 16N600
BTZ 40...45	Aeg	Thy						
BU								
BU		Si-N	=2SD1005-BU (SMD-Marking)		39	SOT-89		›2SD1005
BU		Si-P	=BCX 71RG (SMD-Marking)		35	SOT-23		›BCX 71RG
BU 4 S01...BU 4Sxx	Rhm	CMOS-Logic	Standard CMOS-Logic 4000-Serie		MDIP	SMD		-
BU 74 HC00...HC374	Rhm	CMOS-Logic	Standard TTL-Logic Serie 74xx in CMOS-Techn.					... 74HC...
BU 100	Sgs	Si-N	TV-HA(90°), 150/60V, 10A, 15W(Tc=75°), 100MHz		23a	TO-3	2SC3263	18j BU 109, BUY 69C, BUY 70C, (BU 606...608)[7]
BU 100 A		Si-N	=BU 100: 150/100V, 25W(Tc=100°)		23a	TO-3	2SC3263	18j BU 109, BUY 69C, BUY 70C, (BU 606...608)[7]
BU 102	Sgs	Si-N	TV-HA(110°), 400/150V, 7/10A, 50W(Tc=50°), 80MHz		23a	TO-3	BU 608	23a BU 104, BU 606, BU 608
BU 103	Tho	Si-N	S P, TV-VA, 120/100V, 1A, 15W(Tc=25°), 15MHz		2a	TO-39	(MJE 340)	14h BU 125(S), BUY 41, 2SC1860

Original	Fabric.	Constr.	Info	{Compl. Fig.		JAEGER	Fig.	International
BU 103 A		Si-N	=BU 103, 120/100V, 1A, 30W, 100MHz	22a	TO-66	2SD1138	17j	BUX 67, 2SC782…783, 2SD610
BU 104	Tho	Si-N	TV-HA(110°), 400/150V, 7/15A, 85W, sat<2,5V(7A)	23a	TO-3	BU 608	23a	BU 606, BU 608
BU 104 D		Si-N+Di	=BU 104: + integr. Damper-Diode (3,5A)	23a	TO-3	BU 606 D	23a	BU 606D, BU 608D
BU 104 DP		Si-N+Di	=BU 104 P: + integr. Damper-Diode (3,5A)	17j	TO-220	BU 406 D	17j	BU 406D, BU 408D, 2SC3176
BU 104 P		Si-N	=BU 104: 50W	17j	TO-220	BU 406	17j	BU 406, BU 408, 2SC3175, 2SC3591
BU 105	Aeg,Phi,++	Si-N	TV-HA, 1500V, 2,5A, 10W(Tc=90°), sat<5V(2,5A)	23a	TO-3	BU 208 A	23a	BU 205, BU 208(A), 2SC2928, 2SD350(A),++
BU 106	Rca,Sgs,Tix	Si-N	TV-HA, 325/140V, 10A, 50W, sat<5V(4A)	23a	TO-3	BU 608[7]	23a	BU 109, BUY 69C, BUY 70C, (BU 606…608)[7]
BU 107	Rca,Sgs,Tix	Si-N	TV-HA, 300/120V, 10A, 50W, sat<1,5V(7A)	23a	TO-3	BU 608[7]	23a	BU 109, BUY 69C, BUY 70C, (BU 606…608)[7]
BU 108	Aeg,Phi,++	Si-N	CTV-HA,1500/750V, -/5A, 12,5W(Tc=95°),sat<5V(4,5A)	23a	TO-3	BU 208 A	23a	BU 208(A), 2SC2928, 2SD350(A), 2SD820,++
BU 109	Tho	Si-N	TV-HA(110°), 330/120V, 10/15A, 85W, sat<2V(7A)	23a	TO-3	BU 608[7]	23a	BUY 69C, BUY 70C, (BU 606…608)[7]
BU 109 D		Si-N+Di	=BU 109: + integr. Damper-Diode (5A)	23a	TO-3	BU 606 D[7]	23a	(BU 104D, BU 606D…608D)[7]
BU 109 DP		Si-N+Di	=BU 109P: + integr. Damper-Diode (5A)	17j	TO-220	BU 406 D[7]	17j	(BU 406D…408D, 2SC3176)[7]
BU 109 NP		Si-N	=BU 109	23a	TO-3	BU 606 D	23a	(→BU 109)
BU 109 P		Si-N	=BU 109: 50W	17j	TO-220	BU 406[7]	17j	(BU 406…408, 2SC3175, 2SC3591)[7]
BU 110	Sie	Si-N	TV-HA, 330/150V, 10/15A, 60W(Tc=75°), sat<1,5V(7A)	23a	TO-3	BU 608[7]	23a	BU 109, BUY 69C, BUY 70C, (BU 606…608)[7]
BU 111	Sie	Si-N	TV SMPS, 500/300V, 6/8A, 50W(Tc=75°), sat<1,5V	23a	TO-3	BU 426 A	18j	BU 326(A), BU 426(A), BU 526, 2SC3041
BU 112	Tho	Si-N	CTV-HA(90°), 550/275V, 10A, 85W(Tc=30°)	23a	TO-3	S 2530 A	23a	BU 526, BU 626A, BUY 69C, 2SC2122…23
BU 113(S)	Tho	Si-N	TV-HA(110°), 700/275V, 10A, 85W(Tc=30°), sat<3V BU 113S: 700/300V, sat<1,5V(8A)	23a	TO-3	S 2530 A	23a	BU 526, BU 626A, BUY 69B, 2SC2122…23
BU 114	Sie	Si-N	TV SMPS, 350/225V, 6/8A, 50W(Tc=75°), sat<1,5V(3A)	23a	TO-3	BU 608	23a	BU 104, BU 109, BU 526, BU 606…608
BU 115	Sgs	Si-N	TV-HA, 800/600V, 15/20A, 50W(Tc=75°), sat<1V(10A)	23a	TO-3	(S 2530A)[7]	23a	(BU 526, BU 626A)[7]
BU 116	Sgs	Si-N	=BU 115: 400/300V, sat<1,2V(6A)	23a	TO-3	(S 2530A)[7]	23a	(BU 526, BU 626A)[7]
BU 117	Sgs	Si-N	=BU 115: 250/200V	23a	TO-3	(S 2530A)	18j	(BU 526, BU 626A)[7]
BU 118	Phi	Si-N+Di	TV-HA, 400/200V, 7/10A, 60W, sat<1V(5A)	17j	TO-220	BU 406 D	17j	BU 104DP, BU 109DP, BU 406D, BU 408D, ++
BU 120	Rca,Sgs	Si-N	TV-HA, 400/200V, 10/15A, 50W(Tc=75°), sat<1V(4A)	23a	TO-3	(BU 608)[7]	23a	BUY 69C, BUY 70C, (BU 606, BU 608)[7]
BU 121	Sgs	Si-N	TV-HA, 400/200V, 10/15A, 50W(Tc=75°), sat<1,2V(6A)	23a	TO-3	(BU 608)[7]	23a	BUY 69C, BUY 70C, (BU 606, BU 608)[7]
BU 122	Sgs	Si-N	TV-VA, 250/150V, 5A, 67W(Tc=75°), sat<1V(4A)	23a	TO-3	BU 608	23a	BU 104, BU 109, BU 606…608, 2SD1154
BU 123	Sgs	Si-N	=BU 122: 180/120V, 50W(Tc=75°), sat<2,2V(3A)	23a	TO-3	BU 608	23a	BU 104, BU 109, BU 606…608, 2SD1154
BU 124	Tix	Si-N	TV-HA, 350/150V, 10/15A, 50W, sat<1V(8A)	18j	TO-3P	BU 426 A[7]	18j	(BU 426, BU 926)[7]
BU 124 A		Si-N	=BU 124: 400/150V	18j	TO-3P	BU 426 A[7]	18j	(BU 426, BU 926)[7]
BU 125	Sgs	Si-N	S P, TV-HA, 130/60V, 7A, 10W(Tc=50°), sat<1,2V(5A)	2a	TO-39	(BU 406)[6]	17j	BUY 47…48, BUY 68, BUY 81,(BU 406…408)[6]
BU 125 S		Si-N	=BU 125: 250/150V, 3A, sat<1,5V(0,5A)	2a	TO-39	(BU 406)[6]	17j	BUY 41, BUX 49, (BU 406…408)[6]
BU 126(A,S,T)	EUR,Tos	Si-N	TV-SMPS, 750/300V, 3/6A, 50W, sat<10V(2,5A) A=750/250V, S=750/350V, T=750/375V	23a	TO-3	BU 426 A	18j	BU 326, BU 426, BU 526, BU 926
BU 127	Sgs	Si-N	S P, 200/120V, 10A, 62W, 70MHz, sat<0,7V(5A)	23a	TO-3	BU 608[7]	23a	BU 109, BUY 18, BUY 69C, BUW 86, BUY 70C
BU 128	Sgs	Si-N	=BU 127: 300/200V, 80MHz	23a	TO-3	BU 608[7]	23a	BU 109, BUY 18, BUY 69C, BUW 87, BUY 70C
BU 129	Tho	Si-N	TV-HA(110°), 400V, 5A, 25W(Tc=100°), sat<3V(5A)	23a	TO-3	BU 608	23a	BU 104, BU 606, BU 608
BU 130	Phi	Si-N	TV-HA, 330/150V, 10/15A, 15W(Tc=100°), sat<2V(10A)	23a	TO-3	BU 608[7]	23a	BU 109, BUY 69C, BUY 70C, (BU 606…608)[7]
BU 131	Phi	Si-N	TV-HA, 750/300V, 10/15A, 40W(Tc=60°), sat<1,5V(5A)	23a	TO-3	S 2530 A	23a	BU 526, BU 626A, BUY 69B, BUY 70B
BU 132	Phi	Si-N	TV-VA, 800/600V, 1A, 15W(Tc=97°), sat<5V(0,25A)	23a	TO-3	BUW 11 A	18j	BU 126, 2SC1101, 2SC1167
BU 133	Mot,Phi,Rca	Si-N	S P, 750/250V, 3/6A, 30W(Tc=50°), 8MHz, sat<5V(4A)	23a	TO-3	BU 426 A	18j	BU 326, BUS 11, BUX 82, 2SC3091, 2SC3155
BU 134	Tho	Si-N	S P, TV-SN, 500/350V, 4A, 85W, sat<1V(3A)	23a	TO-3	BU 426 A	18j	BU 326, BU 426, BU 526, BU 926
BU 135	Mot	Si-N	S P, 500/250V, 3A, 30W(Tc=50°), 8MHz, sat<5V(4A)	23a	TO-3	BU 426 A	18j	BU 126, BU 326, BU 426, BUX 45
BU 136	Mot	Si-N	=BU 135: 600/250V, 7A	23a	TO-3	BU 426 A	18j	BU 326, BU 426, BU 526, BU 926
BU 137	Tix	Si-N	S P, 1000/1000V, 12A, 70W, sat<2,2V(5,5A)	23a	TO-3	S 2530 A	23a	BU 157, BU 626A, BUS 13A, 2SD1094
BU 137 A		Si-N	=BU 137: 1200/1000V, 10A	23a	TO-3	2SD1279	23a	BU 157, MJ 8504, 2SC3061, 2SD1279
BU 138	Tho	Si-N+Di	TV-HA, 160/125V, 10A, 60W(Tc=95°), sat<0,5V(5A)	23a	TO-3	BU 606 D[7]	23a	BU 109D, (BU 606D…608D)[7]
BU 139	Tho	Si-N+Di	=BU 138: 200/150V, sat<1V(5A)	23a	TO-3	BU 606 D[7]	23a	BU 109D, (BU 606D…608D)[7]
BU 140	Tho	Si-N+Di	=BU 138: 280/175V, sat<1,5V(5A)	23a	TO-3	BU 606 D[7]	23a	BU 109D, (BU 606D…608D)[7]
BU 141	Tho	Si-N+Di	=BU 138: 330/175V, sat<1,5V(7A)	23a	TO-3	BU 606 D[7]	23a	BU 109D, (BU 606D…608D)[7]
BU 142	Tho	Si-N	S P, 900/350V, 12A, 70W, sat<1,5V(8A)	23a	TO-3	(S 2530A)[7]	23a	BUS 13A, BUW 46, (BU 626A, 2SD1094)[7]
BU 143	Tho	Si-N	=BU 142: 800/350V	23a	TO-3	(S 2530A)[7]	23a	BUS 13, BUW 45…46, (BU 626A, 2SD1094)[7]
BU 144	Tho	Si-N	=BU 142: 700/350V	23a	TO-3	(S 2530A)[7]	23a	BUS 13, BUW 45…46, (BU 626A, 2SD1094)[7]
BU 157	Tix	Si-N	TV-HA, 1500/650V, 12A, 70W, sat<5V(6A)	23a	TO-3	(BU 508A)[7]	18j	BU 2525A, 2SC3995…96, 2SC4288A
BU 180	Tix	Si-N-Darl+Di	TV-HA, 320V, 10A, 50W, hFE>200, sat<1,5V(4A)	18j	TO-3P	(BU 826)[7]	18j	(BU 284, BU 289, BU 826)[7]
BU 180 A		Si-N-Darl+Di	=BU 180: 400V	18j	TO-3P	(BU 826)[7]	18j	(BU 284, BU 826)[7]
BU 181	Tix	Si-N-Darl	TV-HA/SMPS,600V, 10/16A, 65W, hFE>200,sat<1,5V(4A)	18j	TO-3P	BU 826[1]	18j	-
BU 181 A		Si-N-Darl	=BU 181: 800V	18j	TO-3P	BU 826[1]	18j	-
BU 184	Tho	Si-N-Darl+Di	TV-HA/SMPS, 400/200V, 8/15A, 60W, sat<1,5V(5A)	17j	TO-220	BU 806	17j	BU 806
BU 189	Tho	Si-N-Darl+Di	=BU 184: 330/150V	17j	TO-220	BU 806	17j	BU 806…807
BU 204(A)	EUR,Tos	Si-N	CTV-HA, 1300/600V, 2,5/3A, 10W(Tc=90°), sat<5V(2A) A: sat<1,5V(2A)	23a	TO-3	BU 208 A	23a	BU 207(A)…208(A), 2SC1922, 2SD818,++
BU 205(A)	EUR,Tos	Si-N	=BU 204: 1500/700V	23a	TO-3	BU 208 A	23a	BU 208(A), 2SC1922, 2SD3023, 2SD818,++
BU 206	EUR,Tos	Si-N	=BU 204: 1700/800V	23a	TO-3	BU 209	23a	BU 209(A), 2SD784…785
BU 207(A)	EUR,Hit,Tos	Si-N	CTV-HA, 1300/600V, 5/7,5A, 12,5W(Tc=95°), sat<5V A: sat<1V(4,5A)	23a	TO-3	BU 208 A	23a	BU 208(A), 2SC2928, 2SD350(A), 2SD820,++
BU 208(A)	EUR,Hit,Tos	Si-N	=BU 207: 1500/700V	23a	TO-3	BU 208 A	23a	BU 508(A), 2SC2928, 2SD350(A), 2SD820,++
BU 208 D		Si-N+Di	=BU 208: + integr. Damper-Diode	23a	TO-3	BU 208 D	23a	BU 508D, BU 800, 2SD1171…1175
BU 209(A)	EUR,Hit,Tos	Si-N	=BU 207: 1700/800V, 4A, sat<5V(3A)	23a	TO-3	BU 209*	23a	2SD784…785
BU 210	Sie	Si-N	S P, TV-HA, 400/250V, 12/17A, 85W(Tc=45°)	23a	TO-3	(S 2530A)[7]	23a	BUW 74, 2SC2123, (BU 626A, BUY 69C)[7]
BU 211	Sie	Si-N	=BU 210: 600/300V	23a	TO-3	(S 2530A)[7]	23a	BUW 75, 2SC2123, (BU 626A, BUY 69B)[7]
BU 212	Sie	Si-N	=BU 210: 750/350V	23a	TO-3	(S 2530A)[7]	23a	BUW 76…77, 2SC2123, (BU 626A, BUY 69B)[7]
BU 213	Fer	Si-N	S P, 150/60V, 7,5A, 38W(Tc=45°), sat<0,75(7,5A)	22a	TO-66			BUW64A…B, 2SC1863…64, 2SC2334, 2SC3834
BU 214	Fer	Si-N	S P, 150/60V, 10A, 50W(Tc=45°), sat<0,7V(10A)	22a	TO-66			BUS 36…37, BUV 27(A)…28, 2SC2867
BU 215	Fer	Si-N	S P, 150/60V, 20A, 60W(Tc=45°), sat<0,8V(20A)	22a	TO-66			BUV 26
BU 216	Fer	Si-N	S P, 150/60V, 7,5A, 50W(Tc=45°), sat<1V(7,5A)	23a	TO-3			BUW 86…87, 2SC2769, 2SC3835
BU 217	Fer	Si-N	S P, 150/60V, 10A, 60W(Tc=45°), sat<1V(10A)	23a	TO-3			BUW 70, BUY 55, 2SC2769, 2SC2944
BU 218	Fer	Si-N	S P, 150/60V, 20A, 115W(Tc=45°), sat<1,1V(20A)	23a	TO-3			BUV 10, BUW 57…58, BUX 10, BUX 70, ++
BU 221	Sgs	Si-N	S P, TV-HA, 800, 15A, 100W, sat<1,2V(4A)	23a	TO-3	(S 2530A)[7]	23a	BUS 13(A), BUW 45…46, 2SC3996, 2SC4288A
BU 222	Mot	Si-N	S P, 450/350V, 6A, 75W, >10Mhz, sat<1,5V(4A)	23a	TO-3	BU 426 A	18j	BUX15, BUX18C, BUX44, 2SC2656, 2SC3040++
BU 222 A		Si-N	=BU 222: 525/475V	23a	TO-3	BU 426 A	18j	BUX 15, 2SC2536, 2SC3041, 2SD640, ++
BU 223	Mot	Si-N	S P, 450/400V, 10A, 125W, 7,5MHz, sat<1,3V(7A)	23a	TO-3	BUW 13 A	18j	BUW24, BUW72, BUX14, 2SC2625, 2SC4138,++
BU 223 A		Si-N	=BU 223: 525/475V	23a	TO-3	(S 2530A)[7]	23a	BUW34, BUY69, BUW25, 2SC2441, 2SC4157,++
BU 225	Aeg	Si-N	TV-HA, 2200/800V, 2A, 10W(Tc=80°), sat<10V(1,5A)	23a	TO-3			BUY 71, 2SD621, 2SD838
BU 226	Aeg	Si-N	TV-HA, 2000/800V, 1,5A, 32W, sat<10V(1A)	23a	TO-3			BU 225, BUY 71, 2SD621, 2SD838
BU 284	Tho	Si-N-Darl+Di	=BU 184: 90W	18j	TO-3P	BU 826	18j	BU 180A
BU 287	Aeg	Si-N	TV-SMPS, 1300/600V, 8A	23a	TO-3	BU 908	23a	BU 908
BU 289	Tho	Si-N-Darl+Di	=BU 189: 90W	18j	TO-3P	BU 826	18j	BU 180
BU 306 F	Phi	Si-N	S P, HA, 600/300V, 8/16A, 20W, <1,1/3,7µs,sat<1,5V	17c	SOT-186	BUT 12 AF	17c	BUT 12(A)F, 2SC4056, 2SC4441, 2SC4546
BU 307 F	Phi	Si-N	=BU 306F: 700/400V	17c	SOT-186	BUT 12 AF	17c	BUT 12(A)F, BUT 22CF
BU 308	Tix	Si-N	TV-HA, 1500/750V, 5/7,5A, 12,5W(Tc=95°), sat<5V	23a	TO-3	BU 208 A	23a	BU 208(A), 2SC2928, 2SD350(A), 2SD820,++
BU 310	Sie	Si-N	TV-HA, 160/100V, 6/8A, 25W(Tc=100°), sat<0,5V(5A)	23a	TO-3	BU 608	23a	BU 104, BU 109, BU 606…608, 2SD1154
BU 311	Sie	Si-N	=BU 310: 200/125V, sat<1V(5A)	23a	TO-3	BU 608	23a	BU 104, BU 109, BU 606…608, 2SD1154

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
BU 312	Sie	Si-N	=BU 310: 280/150V, sat<1,5V(5A)		23a	TO-3	BU 608	23a	BU 104, BU 109, BU 606...608, 2SD1154
BU 322	Mot	Si-N-Darl	S P, 450/400V, 7A, 100W, sat<1,7V(4A)		23a	TO-3	BU 826[1]	18j	2SD520...521, 2SD528, 2SD705, 2SD707, ++
BU 322 A		Si-N-Darl	=BU 322: 525/475V		23a	TO-3	BU 826[1]	18j	2SD520...521, 2SD528, 2SD705, 2SD707, ++
BU 323	Mot,Rca	Si-N-Darl	S P, 500/350V, 10/16A, 175W, hFE>150,sat<2,7V(10A)		23a	TO-3	(BU 826)[1]	18j	MJ 10013...10014, 2SD683
BU 323 A		Si-N-Darl	=BU 323: 600/400V		23a	TO-3	(BU 826)[1]	18j	MJ 10013...10014, 2SD683
BU 323(A)P		Si-N-Darl	=BU 323:		18j	TO-3P	(BU 826)[1]	18j	BUT 51P, BUV 90
BU 325	Sgs	Si-N	S P, 200/200V, 3A, 25W, 0,3/1µs, sat<1,5V(0,5A)		14h	TO-126			-
BU 326	EUR	Si-N	TV-SMPS, 800/375V, 6/8A, 75W, <0,5/4µs, sat<3V(4A)		23a	TO-3	BU 426 A	18j	BU 426(A), BU 526, BU 926
BU 326 A,R		Si-N	=BU 326: 900/400V		23a	TO-3	BU 426 A	18j	BU 426A, BU 526, BU 926
BU 326(A)P		Si-N	=BU 326(A): 110W		18j	TO-3P	BU 426 A	18j	BU 426(A), BU 926
BU 326 S		Si-N	=BU 326: 800/400V		23a	TO-3	BU 426 A	18j	BU 426(A), BU 526, BU 926
BU 361	Tix	Si-N	S P, 800/800V, 12A, 70W, sat<3,5V(8A)		23a	TO-3	S 2530 A	23a	BU 157, BU 626A, BUW 77, 2SC2123
BU 400	Sgs	Si							
BU 406(H)	EUR,Say,Tos	Si-N	TV-HA, 400/200V, 7/10A, 60W, <-/750ns, sat<1V(5A)		17j	TO-220	BU 406	17j	BU 104P, BU 408, 2SC3175, 2SC3591
BU 406 D		Si-N+Di	=BU 406: + integr. Damper-Diode		17j	TO-220	BU 406 D	17j	BU 104DP, BU 408D, 2SC3176
BU 406 F	Phi	Si-N	=BU 406: Iso, 18W		17c	SOT-186	(BU 406)[3]	17j	BU 306...307F, 2SC4440
BU 407(H)	EUR,Say,Tos	Si-N	=BU 406: 330/150		17j	TO-220	BU 406	17j	BU 109P, BU 406, BU 408, 2SC3173, ++
BU 407 D		Si-N+Di	=BU 407: + integr. Damper-Diode		17j	TO-220	BU 406 D	17j	BU 109DP, BU 406D, BU 408D, 2SC3174
BU 407 F	Phi	Si-N	=BU 407: Iso, 18W		17c	SOT-186	(BU 406)[3]	17j	BU 306...307F
BU 408		Si-N	=BU 406: <-/400ns, sat<1V(6A)		17j	TO-220	BU 406	17j	BU 104P, BU 406, 2SC3175, 2SC3591
BU 408 D		Si-N+Di	=BU 408: + integr. Damper-Diode		17j	TO-220	BU 406 D	17j	BU 104DP, BU 406D, 2SC3176
BU 409	Sgs	Si-N	S P, 250/150V, 7A, 60W, <-/750ns, sat<1V(3A)		17j	TO-220	BU 406	17j	BU 104P, BU 406...408, BUT 54, BUT 56(A)
BU 410	Sie,Tos	Si-N+Di	TV-HA, 160/125V, 8/12A, 50W(Tc=50°), sat<0,5V(5A)		23a	TO-3	BU 606 D	23a	BU 104D, BU 109D, BU 606D...608D
BU 411	Sie,Tos	Si-N+Di	=BU 410: 220/150V, sat<1V(5A)		23a	TO-3	BU 606 D	23a	BU 104D, BU 109D, BU 606D...608D
BU 412	Sie,Tos	Si-N+Di	=BU 410: 280/175V, sat<1,5V(5A)		23a	TO-3	BU 606 D	23a	BU 104D, BU 109D, BU 606D...608D
BU 413	Sie	Si-N+Di	=BU410: 330/175V, 10/15A, 60W(Tc=50°),sat<1,5V(7A)		23a	TO-3	BU 606 D[7]	23a	BU 109D, (BU 104D, BU 606D...608D)[7]
BU 414	Sie	Si-N+Di	S P, TV-HA, 800/400V, 8A, 60W(Tc=75°), sat<3V(5A)		23a	TO-3	BU 426 A[2]	18j	(BU 426(A), BU 526, BU 626A, BU 926)[2]
BU 414 B		Si-N+Di	=BU 414: 900/400V		23a	TO-3	BU 426 A[2]	18j	(BU 426A, BU 526, BU 626A, BU 926)[2]
BU 415	Sie,Tos	Si-N+Di	S P, TV-HA, 800/400V, 12A, 120W, sat<3V(8A)		23a	TO-3	BU 415 B	23a	(BU 626A, 2SC2123)[2]
BU 415 B		Si-N+Di	=BU 415: 900/400V		23a	TO-3	BU 415 B	23a	(BU 626A, 2SC2123)[2]
BU 426	EUR	Si-N	TV-SMPS, 800/375V, 6/8A, 70W(Tc=73°), <600/4250ns		18j	TO-3P	BU 426 A	18j	BU 926
BU 426 A		Si-N	=BU 426: 900/400V		18j	TO-3P	BU 426 A	18j	BU 926
BU 426 F,AF	Aeg	Si-N	=BU 426(A): Iso		18c				-
BU 426 FI,AFI	Tho	Si-N	=BU 426(A): Iso		18c	TO-3P Iso			-
BU 433	Phi	Si-N	=BU 426: 800/375V		18j	TO-3P	BU 426 A	18j	BU 426(A), BU 926
BU 500	Aeg,Mot,Tix	Si-N	CTV-HA, 1500/700V, 6/16A, 75W(Tc=30°),sat<1V(4,5A)		23a	)O-3	BU 508 A	18j	BU 508(A), 2SC3025, 2SD725, 2SD821,++
BU 505	Phi,Sgs	Si-N	TV-HA, 1500/700V, 2,5/4A, 75W, sat<5V(4A)		17j	TO-220			BU 506
BU 505 D		Si-N+Di	=BU 505: + integr. Damper-Diode		17j	TO-220			BU 506D
BU 505 DF		Si-N+Di	=BU 505D: Iso, 20W		17c	SOT-186			BU 506DF
BU 505 F		Si-N	=BU 505: Iso, 20W		17c	SOT-186			BU 506F, 2SD1575
BU 506	Phi	Si-N	TV-HA, SMPS, 1500/700V, 5/8A, 100W, sat<5V(3A)		17j	TO-220	BU 508 AT	17j	-
BU 506 D		Si-N+Di	=BU 506: + integr. Damper-Diode		17j	TO-220			-
BU 506 DF		Si-N+Di	=BU 506D: Iso, 20W		17c	SOT-186			-
BU 506 F		Si-N	=BU 506: Iso, 20W		17c	SOT-186			-
BU 508(A)	EUR,Say	Si-N	CTV-HA, 1500/700V, 8/15A, 125W, sat<5V(4,5A) A: sat<1V(4,5A)		18j	TO-3P	BU 508 A	18j	BU 908, BU 2508A, 2SC3687
BU 508 AF	Phi	Si-N	=BU 508A: Iso, 34W		16c	SOT-199	BU 508 AF	16c	S 2000AF, 2SC3886A, 2SC3896, 2SD1548
BU 508 AT	Tho,Dsi	Si-N	=BU 508A: 75W		17j	TO-220	BU 508 AT	17j	BU 1508AX
BU 508 D		Si-N+Di	=BU 508A: + integr. Damper-Diode		18j	TO-3P	BU 508 D	18j	BU 508D, S 2055A, 2SC3683
BU 508 DF	Phi	Si-N+Di	=BU 508D: Iso, 34W		16c	SOT-199	BU 508 DF	16c	S 2055AF, 2SC3893A, 2SC4124
BU 508 DR	Aeg	Si-N+Di	=BU 508D: + Rbe=25Ω		18j	TO-3P	BU 508 DR	18j	-
BU 508 DRF	Aeg	Si-N+Di	=BU 508DR: Iso, 34W		18c				-
BU 508 FI,DFI	Tho	Si-N(+Di)	=BU 508A,D: Iso, 60W		18c	TO-3P Iso	BU 508 AF	16c	S 2000AF, 2SC3886A, 2SC3886, 2SD1548
BU 508 L		Si-N	=BU 508A		18j	TO-3P	(BU 508A)	18j	›BU 508A
BU 508 V	Phi	Si-N	=BU 508A				BU 508 V		›BU 508A
BU 522	Mot	Si-N-Darl	S P, 400/375V, 7A, 75W, hFE>250, sat<2,5V(4A)		17j	TO-220	BU 806[1]	17j	2SD1533, (BU 806, BU 810)[1]
BU 522 A		Si-N-Darl	=BU 522: 450/425V		17j	TO-220			2SD1533, (BU 810)[1]
BU 522 B		Si-N-Darl	=BU 522: 475/450V		17j	TO-220			2SD1533, (BU 810)[1]
BU 526	Aeg	Si-N	TV-SMPS, 900/400V, 8/10A, 86W, <-/4µs, sat<5V(8A)		23a	TO-3	S 2530 A	23a	BU 626A, BU 926, 2SD1094
BU 526 A		Si-N	=BU 526: 900/460V		23a	TO-3	S 2530 A	23a	BU 626A, 2SD1094
BU 536	Aeg	Si-N	TV-SMPS, 1100/480V, 8/10A, 62W, <4µs		23a	TO-3	BU 908	18j	BU 902, BUV 89
BU 546	Aeg	Si-N	TV-SMPS, 1300/550V, 6/8A, 100W, sat<2V(3,2A)		23a	TO-3	BU 903	18j	BU 903
BU 603	Phi	Si-N	TV-HA, SMPS, 1350/550V, 5/8A, 100W, sat<2V(2A)		17j	TO-220			-
BU 606	Sgs	Si-N	TV-HA, 400/200V, 7/10A, 90W, <-/750ns, sat<1V(5A)		23a	TO-3	BU 608	23a	BU 104, BU 608, BUY 69C
BU 606 D		Si-N+Di	=BU 606: + integr. Damper-Diode		23a	TO-3	BU 606 D	23a	BU 104D, BU 608D
BU 607	Sgs	Si-N	=BU 606: 330/200V		23a	TO-3	BU 608	23a	BU 104, BU 606, BU 608, BUY 69C
BU 607 D		Si-N+Di	=BU 607: + integr. Damper-Diode		23a	TO-3	BU 606 D	23a	BU 104D, BU 606D, BU 608D
BU 608	Sgs	Si-N	=BU 606: <-/400ns, sat<1V(6A)		23a	TO-3	BU 608	23a	BU 104, BU 606, BUY 69C
BU 608 D		Si-N+Di	=BU 608: + integr. Damper-Diode		23a	TO-3	BU 606 D	23a	BU 104D, BU 606D
BU 626(A)	Sie	Si-N	TV-SMPS, 1000/400V, 10/15A, 100W, <-/1µs, sat<3,3V		23a	TO-3	S 2530 A	23a	S 2530A, 2SD1094
BU 705	Aeg,Phi	Si-N	TV-HA, 1500/700V, 2,5/4A, 75W, sat<1V(2A)		18j	TO-3P	BU 705*	18j	BU 706, 2SC3483...84, 2SD1493...95, ++
BU 705 D		Si-N+Di	=BU 705: + integr. Damper-Diode		18j	TO-3P	BU 508D	18j	BU 706D, 2SC3479...80, 2SD1290...91,++
BU 705 DF		Si-N+Di	=BU 705D: Iso, 29W		18c	SOT-199	S 2055 AF	18c	BU 706DF, 2SD1553, 2SD1649, 2SD1876,++
BU 705 F		Si-N	=BU 705: Iso, 29W		18c	SOT-199	(BU 705)[3]*	18j	BU 706F, 2SD1543, 2SD1653, 2SD1882,++
BU 706	Phi,Tho	Si-N	TV-HA/SMPS, 1500/700V, 5/8A, 100W, sat<1V(3A)		18j	TO-3P	BU 508 A	18j	BU 508(A), 2SC3485...86, 2SD1496...97, ++
BU 706 D		Si-N+Di	=BU 706: + integr. Damper-Diode		18j	TO-3P	BU 508 D	18j	BU 508D, 2SC3481...82, 2SC3681, 2SD1878++
BU 706 DF		Si-N+Di	=BU 706D: Iso, 32W		18c	SOT-199	S 2055 AF	18c	BU 508DF, 2SD1555...56, 2SD1651...52,++
BU 706 F		Si-N	=BU 706: Iso, 32W		16c	SOT-199	BU 508 AF	16c	BU 508AF, 2SC4142...43, 2SD1545...46, ++
BU 724	Phi	Si-N-Darl+Di	S P, SMPS, 650/375V, 2/3A, 25W,<1/3µs,sat<5V(0,4A)		≈14j	SOT-82			(BUD 46(A), 2SC3259, 2SC3579)[4]
BU 724 A		Si-N-Darl+Di	=BU 724: 850/400V, sat<3V(0,3A)		≈14j	SOT-82			-[4]
BU 726	Tho	Si-N	TV, -/400V, 7A, 60W(Tc=50°), <0,8/4µs		23a	TO-3	BU 426	18j	BU 426(A), BU 526, BU 536, BU 926
BU 800(A,S)	Mot,Tho	Si-N+Di	CTV-HA, 1500/700V, 5/60A, 60W, sat<5V(4,5A)		23a	TO-3	BU 208 D	23a	BU 208D, BU 508D, 2SD903, 2SD1171...75,++
BU 801		Si-N-Darl+Di	S P, 600/400V, 3A, 40W, hFE>100, <0,8/1,5µs		14h	TO-126	BU 801	14h	-
BU 806	Phi,Sgs,Tix	Si-N-Darl+Di	TV-HA, 400/200V, 8/15A, 60W, sat<1,5V(5A)		17j	TO-220	BU 806	17j	BU 184
BU 806 AF		Si-N-Darl+Di	=BU 806: Iso		17c				-
BU 806 FI	Tho	Si-N-Darl+Di	=BU 806: Iso, 30W		17c	TO-220Iso			-
BU 807	Phi,Sgs,Tix	Si-N-Darl+Di	=BU 806: 330/150V		17j	TO-220	BU 806	17j	BU 184, BU 189
BU 807 FI	Tho	Si-N-Darl+Di	=BU 807: Iso, 30W		17c	TO-220Iso			-
BU 808 DFI [SGS]	Sgs	Si-N-Darl+Di	=BU 808FI: integr. Damper-Diode		18c	TO-3P Iso			-
BU 808 FI [SGS]	Sgs	Si-N-Darl	CTV-HA, 1400/700V, 5/10A, 50W, hFE>25,sat<1,6V(5A)		18c	TO-3P Iso			-
BU 808 [Philips]	Phi	Si-N	3Ph.-Motor Drv, 1500/700V, 12/20A, 160W,sat<1V(9V)		23a	TO-3			BUX 88
BU 810	Sgs	Si-N-Darl+Di	S P, 600/400V, 7/10A, 75W, <0,6/2µs, sat<3V(7A)		17j	TO-220	2SD798	17j	2SC3579, 2SD798...799
BU 824	Phi	Si-N-Darl+Di	S P, 650/375V, 0,5/1A, 12,5W, hFE>325, <1/2,5µs		13h	TO-202			-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BU 826	Phi	Si-N-Darl+Di	S P, 800/375V, 6/8A, 125W, <1,3/2,2µs,sat<2,5V(4A)		18j	TO-3P	BU 826	18j	BUT 50P, 2SC3030, 2SC3032
BU 826 A		Si-N-Darl+Di	=BU 826: 1000/400V		18j	TO-3P			-
BU 900	Tho	Si-N-Darl	Tripleton, 650/400V, 8A, 70W, hFE>7000, sat<4V(3A) El. Zündung/Ignition, Z-Diode(B ›C)		17j	TO-220			-
BU 902	Aeg	Si-N	S P, TV-SMPS, 1100/480V, 8/10A, 100W, sat<5V(4A)		18j	TO-3P	BU 908	18j	BU 508(A), BU 908, BUV 89, 2SC3643
BU 902 F		Si-N	=BU 902: Iso		18c		BU 508 AF	16c	BU 508AF, BU 908F, 2SC3886, 2SC4144
BU 903	Aeg,Phi	Si-N	S P, TV-SMPS, 1350/550V, 6/8A, 125W, sat<2V(3,2A)		18j	TO-3P	BU 903	18j	BU 508(A), BU 908, 2SC3687, 2SD1497
BU 903 F		Si-N	=BU 903: Iso		18c		BU 508 AF	16c	BU 508AF, 2SC3885, 2SC3895, 2SC4143,++
BU 908	Aeg	Si-N	TV-HA/SMPS, 1500/700V, 8/15A, 125W, sat<2V(3.2A)		18j	TO-3P	BU 908	18j	BU 508(A), BU 2508A, 2SC3687
BU 908 AF		Si-N	=BU 908: Iso		18c		BU 508 AF	16c	BU 508AF, BU 2508AF, 2SC3896, 2SC4758,++
BU 910	Sgs	Si-N-Darl+Di	S P, 400/350V, 6/10A, 60W, sat<1,8V(4A)		17j	TO-220	BU 806	17j	BU 806, 2SD799, 2SD1114, 2SD1245
BU 911	Sgs	Si-N-Darl+Di	=BU 910: 450/400V		17j	TO-220	2SD798[2]	17j	2SD799, 2SD1245
BU 912		Si-N-Darl+Di	=BU 910: 500/450V		17j	TO-220	2SD798[2]	17j	2SD799, 2SD1245
BU 920	Sgs	Si-N-Darl+Di	S P, 400/350V, 10/15A, 120W, hFE>300, sat<1,8V(7A)		23a	TO-3			BU 930…932, BUW 66, MJ 10002…03
BU 920 P		Si-N-Darl+Di	=BU 920: 105W		18j	TO-3P			BU 930P…932P, BUT 51P, BUV 90
BU 920 PFI		Si-N-Darl+Di	=BU 920: 55W		18c	TO-3P Iso			-
BU 920 T		Si-N-Darl+Di	=BU 920: 105W		17j	TO-220			2SD1162
BU 921	Sgs	Si-N-Darl+Di	=BU 920: 450/400V		23a	TO-3			BU 931…932, MJ 10002…03
BU 921 P		Si-N-Darl+Di	=BU 921: 105W		18j	TO-3P			BU 931P…932P, BUT 51P, BUV 90
BU 921 PFI		Si-N-Darl+Di	=BU 921: 55W		18c	TO-3P Iso			-
BU 921 T		Si-N-Darl+Di	=BU 921: 105W		17j	TO-220			2SD1162
BU 921 ZP		Si-N-Darl+Di	=BU 921: integr. Z-Diode(B ›C), 350V, 125W		18j	TO-3P			-
BU 921 ZPFI		Si-N-Darl+Di	=BU 921: integr. Z-Diode(B ›C), 350V, 60W		18c	TO-3P Iso			-
BU 921 ZT		Si-N-Darl+Di	=BU 921: integr. Z-Diode(B ›C), 350V, 100W		17j	TO-220			-
BU 921 ZTFI		Si-N-Darl+Di	=BU 921: integr. Z-Diode(B ›C), 350V, 40W		17c	TO-220Iso			-
BU 922	Sgs	Si-N-Darl+Di	=BU 920: 500/450V		23a	TO-3			BU 932, MJ 10003, MJ 10013…14
BU 922 P		Si-N-Darl+Di	=BU 922: 105W		18j	TO-3P			BU 932P, BUT 51P, BUV 90
BU 922 PFI		Si-N-Darl+Di	=BU 922: 55W		18c	TO-3P			-
BU 922 T		Si-N-Darl+Di	=BU 922: 105W		17j	TO-220			2SD1162
BU 926	Tho	Si-N	S P, TV-SMPS, 850/400V, 8A, 90W, sat<1,6V(6A)		18j	TO-3P	BUV 70	18j	BUV 47(A), BUV 70…71, BUV 89, BUW 12(A)
BU 930	Sgs	Si-N-Darl+Di	S P, 400/350V, 15A, 150W, hFE>300, sat<1,8V(10A)		23a	TO-3			BUT 13…15, MJ 10008…09, 2SD711(A),++
BU 930 P		Si-N-Darl+Di	=BU 930: 105W		18j	TO-3P			BUT 51P, 2SD1466
BU 930 Z		Si-N-Darl+Di	=BU 930: integr. Z-Diode(B ›C), 175W		23a	TO-3			-
BU 930 ZP		Si-N-Darl+Di	=BU 930: integr. Z-Diode(B ›C)		18j	TO-3P			-
BU 931	Sgs	Si-N-Darl+Di	=BU 930: 450/400V		23a	TO-3			BUT 13…15, MJ 10008…09, 2SD711(A),++
BU 931 P		Si-N-Darl+Di	=BU 931: 105W		18j	TO-3P			BUT 51P, 2SD1466
BU 931 R		Si-N-Darl+Di	=BU 931: 175W		23a	TO-3			BUT 13…15
BU 931 RP		Si-N-Darl+Di	=BU 931: 125W		18j	TO-3P			BUT 51P, 2SD1466
BU 931 RPFI		Si-N-Darl+Di	=BU 931: 60W		18c	TO-3P Iso			-
BU 931 Z		Si-N-Darl+Di	=BU 931: integr. Z-Diode(B ›C), 350V, 175W		23a	TO-3			-
BU 931 ZP		Si-N-Darl+Di	=BU 931: integr. Z-Diode(B ›C), 350V, 125W		18j	TO-3P			-
BU 931 ZPFI		Si-N-Darl+Di	=BU 931: integr. Z-Diode(B ›C), 350V, 60W		18c	TO-3P Iso			-
BU 932	Sgs	Si-N-Darl+Di	=BU 930: 500/450V		23a	TO-3			BUT 13…15, MJ 10008…09, 2SD711(A),++
BU 932 P		Si-N-Darl+Di	=BU 932: 105W		18j	TO-3P			BUT 51P, 2SD1466
BU 932 R		Si-N-Darl+Di	=BU 932: 175W		23a	TO-3			BUT 13…15
BU 932 RP		Si-N-Darl+Di	=BU 932: 125W		18j	TO-3P			BUT 51P, 2SD1466
BU 932 RPFI		Si-N-Darl+Di	=BU 932: 60W		18c	TO-3P Iso			-
BU 999	Sgs	Si-N	LF,S P, 160/140V, 25/40A, 106W, sat<0,8V(10A)		18j	TO-3P			BUX 69
BU 1085	Tix	Si-N	=BU 108		23a	TO-3	BU 208 A	23a	›BU 108
BU 1200…1206(L)	Rhm	CMOS-IC	Gate Arrays						-
BU 1301 F	Rhm	CMOS-IC	IR-FB Encoder		20-MDIP				-
BU 1508 AX	Phi	Si-N	=BU 2508A: Iso, 35W		17c	TO-220 Iso			-
BU 1508 DX	Phi	Si-N+Di	=BU 2508D: Iso, 35W		17c	TO-220 Iso			-
BU 1706 A	Phi	Si-N	S P,1750/850V, 5/8A, 100W, sat<1V(1,5A),<1,5/7,5µs HF Electr. Lightning Ballast		17j	TO-220			-
BU 1706 AX	Phi	Si-N	=BU 1706A: Iso, 32W		17c	TO-220 Iso			-
BU 1708 AX	Phi	Si-N	S P,1750/850V, 8/15A, 35W, sat<1V(2,5A),<1,3/7,9µs HF Electr. Lightning Ballast		17c	TO-220 Iso			-
BU 2007 F	Rhm	CMOS-Logic	Dual, Inverter, hi-speed, (=2xBU74HCU04)		8-MDIP				-
BU 2029	Rhm	CMOS-IC	12-Bit Serial In Parallel Out Driver, 20mA		16-DIP				-
BU 2029 F	Rhm	CMOS-IC	=BU 2029: SMD		16-MDIP				-
BU 2040	Rhm	CMOS-IC	12-Bit Serial In Parallel Out Driver, 20mA		16-DIP				-
BU 2040 F	Rhm	CMOS-IC	=BU 2040: SMD		16-MDIP				-
BU 2090	Rhm	CMOS-IC	12-Bit Serial In Parallel Out Driver,Udd=2,7…5,5V		16-DIP				-
BU 2090 F		CMOS-IC	=BU 2090: SMD		16-MDIP				-
BU 2090 FS		CMOS-IC	=BU 2090: SMD		16-SMDIP				-
BU 2092	Rhm	CMOS-IC	12-Bit Serial In Parallel Out Driver,Udd=2,7…5,5V		18-DIP				-
BU 2092 F		CMOS-IC	=BU 2092: SMD		18-MDIP				-
BU 2105 CH-2W	Rhm	CMOS-IC	64-Bit Serial In Parallel Out Driver, 42mA, 5MHz		Wafer				-
BU 2112 F	Rhm	CMOS-IC	SMD, Ni-Cd Battery Charge Controller, 8-Bit PWM		18-MDIP				-
BU 2114	Rhm	CMOS-IC	8-Bit Shift Register, Latch Driver, Udd=5V, 36mA		18-DIP				-
BU 2114 F		CMOS-IC	=BU 2114: SMD		18-MDIP				-
BU 2120 CH-3W	Rhm	CMOS-IC	64-Bit Thermal Driver		Chip				-
BU 2130 K1	Rhm	MOS-IC	Telecom,Fax, Halbton-/Halftone Processor		80-MP				-
BU 2302	Rhm	CMOS-IC	CR Timer, Ucc=1,8…6V		8-DIP				-
BU 2302 F	Rhm	CMOS-IC	=BU 2302: SMD		8-MDIP				-
BU 2305	Rhm	CMOS-IC	CR Timer, Ucc=1,8…6V		8-DIP				-
BU 2305 F	Rhm	CMOS-IC	=BU 2305: SMD		8-MDIP				-
BU 2400(L)	Rhm	CMOS-µC-IC	4 Bit, 64x4-Bit RAM, 1024x8-Bit ROM		40-DIP				-
BU 2403(L)	Rhm	CMOS-µC-IC	4 Bit, 16x4-Bit RAM, 640x8-Bit ROM		18-MDIP				-
BU 2404(L)	Rhm	CMOS-µC-IC	4 Bit, 16x4-Bit RAM, 640x8-Bit ROM		18-DIP				-
BU 2405(L)	Rhm	CMOS-µC-IC	4 Bit, 16x4-Bit RAM, 512x8-Bit ROM		16-DIP				-
BU 2406(L)	Rhm	CMOS-µC-IC	4 Bit, 16x4-Bit RAM, 512x8-Bit ROM		18-MDIP				-
BU 2407(L)	Rhm	CMOS-µC-IC	4 Bit, 16x4-Bit RAM, 512x8-Bit ROM		18-SQP				-
BU 2408 A,AL	Rhm	CMOS-µC-IC	4 Bit, 16x4-Bit RAM, 512x8-Bit ROM		18-MDIP				-
BU 2409 A,AL	Rhm	CMOS-µC-IC	4 Bit, 16x4-Bit RAM, 512x8-Bit ROM		18-DIP				-
BU 2411(L)	Rhm	CMOS-µC-IC	4 Bit, 16x4-Bit RAM, 1024x8-Bit ROM		30-SDIP				-
BU 2412(L)	Rhm	CMOS-µC-IC	4 Bit, 16x4-Bit RAM, 1024x8-Bit ROM		28-MDIP				-
BU 2413(L)	Rhm	CMOS-µC-IC	4 Bit, 16x4-Bit RAM, 1024x8-Bit ROM		32-SDIP				-
BU 2414(L)	Rhm	CMOS-µC-IC	4 Bit, 16x4-Bit RAM, 1024x8-Bit ROM		42-SDIP				-
BU 2415(L)	Rhm	CMOS-µC-IC	4 Bit, 16x4-Bit RAM, 1024x8-Bit ROM		40-MDIP				-
BU 2416(L)	Rhm	CMOS-µC-IC	4 Bit, 16x4-Bit RAM, 1024x8-Bit ROM		44-MP				-
BU 2417(L)	Rhm	CMOS-µC-IC	4 Bit, 16x4-Bit RAM, 1024x8-Bit ROM		32-MP				-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BU 2418(L)	Rhm	CMOS-µC-IC	4 Bit, 32x4-Bit RAM, 1024x8-Bit ROM		22-MDIP				-
BU 2418 L	Rhm	CMOS-µC-IC	4 Bit, 32x4-Bit RAM, 1024-Bit ROM		22-MDIP				-
BU 2419(L)	Rhm	CMOS-µC-IC	4 Bit, 32x4-Bit RAM, 1024x8-Bit ROM		22-DIP				-
BU 2421	Rhm	µC-IC	4 Bit, 64x4-Bit RAM, 1024x8-Bit ROM		32-SDIP				-
BU 2422(L)	Rhm	CMOS-µC-IC	4 Bit, 32x4-Bit RAM, 1024x8-Bit ROM		22-SDIP				-
BU 2424(L)	Rhm	CMOS-µC-IC	4 Bit, 64x4-Bit RAM, 1024x8-Bit ROM		40-MP				-
BU 2425	Rhm	CMOS-µC-IC	4 Bit, 64x4-Bit RAM, 1024x8-Bit ROM		32-MP				-
BU 2430(L)	Rhm	CMOS-µC-IC	4 Bit, 32x4-Bit RAM, 1024x8-Bit ROM		20-MDIP				-
BU 2492	Rhm	CMOS-µC-IC	4 Bit, 64x4-Bit RAM, external EPROM		100-MP				-
BU 2493	Rhm	CMOS-µC-IC	4 Bit, 64x4-Bit RAM, external EPROM		100-MP				-
BU 2494	Rhm	CMOS-µC-IC	4 Bit, 32x4-Bit RAM, external EPROM		80-MP				-
BU 2495	Rhm	CMOS-µC-IC	4 Bit, 16x4-Bit RAM, external EPROM		64-MP				-
BU 2496	Rhm	CMOS-µC-IC	4 Bit, 16x4-Bit RAM, external EPROM		42-SDIP				-
BU 2497	Rhm	CMOS-µC-IC	4 Bit, 16x4-Bit RAM, external EPROM		42-SDIP				-
BU 2498	Rhm	CMOS-µC-IC	4 Bit, 64x4-Bit RAM, external EPROM		64-MP				-
BU 2506 DF	Phi	Si-N+Di	CTV-HA, 1500/700V, 5/8A, 45W, sat<1V(3A)		16c	SOT-199	2SD1555	18c	BU 2508DF, 2SC3892A, 2SC4765, 2SC4916
BU 2506 DX		Si-N+Di	=BU 2506DF:		18c	TO-3P Iso	2SD1555	18c	›BU 2506DF
BU 2508 A	Phi	Si-N	CTV-HA, 1500/700V, 8/15A, 125W, sat<5V(4,5A)		18j	TO-3P	BU 2508 A	18j	2SC3687…88
BU 2508 AF		Si-N	=BU 2508A: Iso, 45W		16c	SOT-199	BU 2508 AF	16c	2SC3886A, 2SC3896, 2SC4542, 2SC4758,++
BU 2508 AX		Si-N	=BU 2508A: Iso, 45W		18c	TO-3P Iso	BU 2508 AF	16c	›BU 2508AF
BU 2508 D		Si-N+Di	=BU 2508A: + integr. Damper-Diode		18j	TO-3P			2SC3683…84
BU 2508 DF		Si-N+Di	=BU 2508D: Iso, 45W		16c	SOT-199			2SC3893A, 2SC4763
BU 2508 DX		Si-N+Di	=BU 2508D: Iso, 45W		18c	TO-3P Iso			›BU 2508DF
BU 2520 A	Phi	Si-N	CTV-HA, hi-res, 1500/800V, 10/25A, 125W,sat<5V(6A)		18j	TO-3P	2SC3688	18j	BU 2522A, 2SC3688
BU 2520 AF		Si-N	=BU 2520A: Iso, 45W		16c	SOT-199	2SC4924	18c	BU 2522AF, 2SC4542
BU 2520 AX		Si-N	=BU 2520A: Iso, 45W		18c	TO-3P Iso	2SC4924	18c	›BU 2520AF
BU 2520 D		Si-N+Di	=BU 2520A: + integr. Damper-Diode		18j	TO-3P			2SC3684
BU 2520 DF		Si-N+Di	=BU 2520D: Iso, 45W		16c	SOT-199			2SC4763
BU 2520 DX		Si-N+Di	=BU 2520D: Iso, 45W		18c	TO-3P Iso			›BU 2520DF
BU 2522 A	Phi	Si-N	CRT-HA, hi-res, 1500/800V, 10/25A, 125W,sat<5V(6A)		18j	TO-3P	2SC3688	18j	2SC3688
BU 2522 AF		Si-N	=BU 2522A: Iso, 45W		16c	SOT-199	2SC4924	18c	2SC4542
BU 2522 AX		Si-N	=BU 2522A: Iso, 45W		18c	TO-3P Iso	2SC4924	18c	›BU 2522AF
BU 2525 A	Phi	Si-N	CTV-HA, hi-res, 1500/800V, 12/30A, 125W,sat<5V(8A)		18j	TO-3P			BU 2527A, BUH 1015
BU 2525 AF		Si-N	=BU 2525A: Iso, 45W		16c	SOT-199			BU 2527AF, 2SC4692
BU 2525 AX		Si-N	=BU 2525A: Iso, 45W		18c	TO-3P Iso			›BU 2525AF
BU 2527 A	Phi	Si-N	CRT-HA, hi-res, 1500/800V, 12/30A, 125W,sat<5V(6A)		18j	TO-3P			BUH 1015
BU 2527 AF		Si-N	=BU 2527A: Iso, 45W		16c	SOT-199			2SC4890…91
BU 2527 AX		Si-N	=BU 2527A: Iso, 45W		18c	TO-3P Iso			›BU 2527AF
BU 2611	Rhm	MOS-IC	AM/FM-Tuner PLL Frequency Synthesizer		16-DIP				-
BU 2611 F	Rhm	MOS-IC	=BU 2611: SMD		16-MDIP				-
BU 2614	Rhm	MOS-IC	AM/FM-Tuner PLL Frequency Synthesizer		16-DIP				-
BU 2614 F	Rhm	MOS-IC	=BU 2614: SMD		16-MDIP				-
BU 2614 FS	Rhm	MOS-IC	=BU 2614: SMD		16-SMDIP				-
BU 2615	Rhm	MOS-IC	AM/FM-Tuner PLL Frequency Synthesizer		20-DIP				-
BU 2615 F	Rhm	MOS-IC	=BU 2615: SMD		20-MDIP				-
BU 2615 FS	Rhm	MOS-IC	=BU 2615: SMD		20-SMDIP				-
BU 2616	Rhm	MOS-IC	AM/FM-Tuner PLL Frequency Synthesizer		18-DIP				-
BU 2616 F	Rhm	MOS-IC	=BU 2616: SMD		18-MDIP				-
BU 2619	Rhm	MOS-IC	AM/FM-Tuner PLL Frequency Synthesizer		20-DIP				-
BU 2619 F	Rhm	MOS-IC	=BU 2619: SMD		20-MDIP				-
BU 2701 F	Rhm	CMOS-IC	Camera, PAL/SECAL Sync. Signal Generator		28-MDIP				-
BU 2702	Rhm	CMOS-IC	VC++, Zeitgeber/Time Base		7-SIP				-
BU 2705 F	Rhm	CMOS-IC	Camera, PAL/SECAL Sync. Signal Generator		28-MDIP				-
BU 2710 S	Rhm	CMOS-IC	VC, Digital Servo		42-SDIP				-
BU 2728 K	Rhm	CMOS-IC	VC, Title Memory Controller, NTSC/PAL/SECAM		44-MP				-
BU 2730 S	Rhm	CMOS-IC	VC, Digital Servo		30-SDIP				-
BU 2762 AL	Rhm	CMOS-IC	VC, Color Signals & Test Patterns, Blue Back Sign.		18-SQP				-
BU 2763 F	Rhm	CMOS-IC	=BU 2763S: SMD		18-MDIP				-
BU 2763 S	Rhm	CMOS-IC	VC, Color Signal Processor f. AFC		18-SDIP				-
BU 2767 S	Rhm	CMOS-IC	VC, Servo, Special Playback(Fine Slow)		32-SDIP				-
BU 2770 S	Rhm	CMOS-IC	VC, Digital Servo		42-SDIP				-
BU 2780 S	Rhm	CMOS-IC	VC, Digital Servo		30-SDIP				-
BU 2790 S	Rhm	CMOS-IC	VC, Digital Servo		42-SDIP				-
BU 2841 AFS	Rhm	CMOS-IC	SMD,VC, Color Sig. & Test Patterns, Blue Back Sig.		20-SMDIP				-
BU 2842 FS	Rhm	CMOS-ROM-IC	SMD, TV,VC, On Sreen Character(128) Display		20-SMDIP				-
BU 2846 AKV	Rhm	CMOS-IC	Camcorder, Title Memory Controller		48-MP				-
BU 2848 FS	Rhm	CMOS-ROM-IC	SMD, On Sreen Character(128) Display, 12x18 Dot		20-SMDIP				-
BU 2870 FS	Rhm	CMOS-ROM-IC	SMD, On Sreen Character(256) Display, 12x18 Dot		20-SMDIP				-
BU 2873 FS	Rhm	CMOS-ROM-IC	SMD, On Sreen Character(64) Display, 12x18 Dot		20-SMDIP				-
BU 2890	Rhm	CMOS-IC	VC, Digital Servo		42-SDIP				-
BU 2902 F	Rhm	CMOS-IC	SMD, Telecom, Ton-/Hold Tone Generator, Ucc=3V		18-MDIP				-
BU 2906 F	Rhm	CMOS-IC	SMD, Telecom, Ton-/Hold Tone Generator, Ucc=3V		18-MDIP				-
BU 2907 F	Rhm	CMOS-IC	SMD, Telecom, Ton-/Hold Tone Generator, Ucc=3V		18-MDIP				-
BU 2908 F	Rhm	CMOS-IC	SMD, Telecom, Ton-/Hold Tone Generator, Ucc=3V		18-MDIP				-
BU 2911	Rhm	CMOS-IC	Türgong/Door Chime, Multi-Melody, Ucc=3V		18-DIP				-
BU 4000…BU 4xxx	Rhm	CMOS-Logic	Standard CMOS-Logic 4000-Serie				›4001…		… 4000…4xxx (CMOS)
BU 8241 F	Rhm	MOS-IC	SMD, Telecom, Cross Point Mixer		24-MDIP				-
BU 8241 FS	Rhm	MOS-IC	=BU 8241F:		24-SMDIP				-
BU 8242 F	Rhm	MOS-IC	SMD, Telecom, Cross Point Mixer		20-MDIP				-
BU 8244 F	Rhm	MOS-IC	SMD, Telecom, Cross Point Mixer		16-MDIP				-
BU 8302 A	Rhm	MOS-IC	Telecom, Ton-/Impulswahl/Tone & Pulse Dialer		24-DIP				-
BU 8304	Rhm	MOS-IC	Telecom, Ton-/Impulswahl/Tone & Pulse Dialer		24-DIP				-
BU 8304 F	Rhm	MOS-IC	=BU 8304: SMD		28-MDIP				-
BU 8307 F,CF	Rhm	MOS-IC	=BU 8307S: SMD		24-MDIP				-
BU 8307 S,CS	Rhm	MOS-IC	Telecom, Ton-/Impulswahl/Tone & Pulse Dialer		22-SDIP				-
BU 8309 AK		MOS-IC	=BU 8309AS: SMD		32-MP				-
BU 8309 AS	Rhm	MOS-IC	Telecom, Ton-/Impulswahl/Tone & Pulse Dialer		32-SDIP				-
BU 8310 AK	Rhm	MOS-IC	Telecom, LED Panal Interface		64-MP				-
BU 8311 KS	Rhm	MOS-IC	Telecom, LED Panal Interface		56-MP				-
BU 8313 K	Rhm	MOS-IC	Telecom, LED Panal Interface		44-MP				-
BU 8320 A	Rhm	MOS-IC	Telecom, Ton-/Impulswahl/Tone & Pulse Rep. Dialer		28-DIP				-
BU 8320 AF	Rhm	MOS-IC	=BU 8320A: SMD		28-MDIP				-
BU 8321	Rhm	MOS-IC	Telecom, Ton-/Impulswahl/Tone & Pulse Rep. Dialer		28-DIP				-

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
BU 8321 F	Rhm	MOS-IC	=BU 8321: SMD		28-MDIP			-
BU 8322	Rhm	MOS-IC	Telecom, Ton-/Impulswahl/Tone & Pulse Rep. Dialer		28-DIP			-
BU 8322 F	Rhm	MOS-IC	=BU 8322: SMD		28-MDIP			-
BU 8323	Rhm	MOS-IC	Telecom, Ton-/Impulswahl/Tone & Pulse Rep. Dialer		28-DIP			-
BU 8323 F	Rhm	MOS-IC	=BU 8323: SMD		28-MDIP			-
BU 8325 K		MOS-IC	=BU 8325S: SMD		32-MP			-
BU 8325 S	Rhm	MOS-IC	Telecom, Ton-/Impulswahl/Tone & Pulse Dialer		32-SDIP			-
BU 8871	Rhm	MOS-IC	Telecom, DTMF Empfänger/Receiver		8-DIP			-
BU 8871 F		MOS-IC	=BU 8871: SMD		18-MDIP			-
BU 8872	Rhm	MOS-IC	Telecom, DTMF Empfänger/Receiver		8-DIP			-
BU 8872 FS		MOS-IC	=BU 8872: SMD		16-SMDIP			-
BU 8874	Rhm	MOS-IC	Telecom, DTMF Empfänger/Receiver		8-DIP			-
BU 8874 F		MOS-IC	=BU 8874: SMD		18-MDIP			-
BU 9250 F	Rhm	CMOS-IC	=BU 9250S: SMD		18-MDIP			-
BU 9250 S	Rhm	CMOS-IC	Audio Digital Delay f. Karaoke Echo, 1kB SRAM		18-DIP			-
BU 9251 F	Rhm	CMOS-IC	=BU 9251S: SMD		18-MDIP			-
BU 9251 S	Rhm	CMOS-IC	Audio Digital Delay f. Karaoke Echo, 1kB SRAM		18-DIP			-
BU 9252 F	Rhm	CMOS-IC	=BU 9252S: SMD		18-MDIP			-
BU 9252 S	Rhm	CMOS-IC	Audio Digital Delay f. Karaoke Echo, 2kB SRAM		18-DIP			-
BU 9500 K	Rhm	DIG-IC	Floppy-Disk, Controller		64-MP			-
BU 9706 KS	Rhm	MOS-IC	LCD Segment Drv, 40 Bit Shift Register, Ucc=3…6V		56-MP			-
BU 12000…12007	Rhm	CMOS-IC	Gate Arrays					-
BU 24201	Rhm	CMOS-µC-IC	4 Bit, 128x4-Bit RAM, 2048x8-Bit ROM		32-SDIP			-
BU 24400(L)	Rhm	CMOS-µC-IC	4 Bit, 256x4-Bit RAM, 4096x8-Bit ROM		64-MP			-
BU 24401 L	Rhm	CMOS-µC-IC	4 Bit, 128x4-Bit RAM, 4096x8-Bit ROM		80-MP			-
BU 24403	Rhm	CMOS-µC-IC	4 Bit, 256x4-Bit RAM, 4096x8-Bit ROM		80-MP			-
BU 24404	Rhm	CMOS-µC-IC	4 Bit, 256x4-Bit RAM, 4096x8-Bit ROM		64-MP			-
BU 24407 L	Rhm	CMOS-µC-IC	4 Bit, 128x4-Bit RAM, 4096x8-Bit ROM		64-MP			-
BU 24410 L	Rhm	CMOS-µC-IC	4 Bit, 256x4-Bit RAM, 4096x8-Bit ROM		80-MP			-
BU 24805 L	Rhm	CMOS-µC-IC	4 Bit, 256x4-Bit RAM, 8192x8-Bit ROM		80-MP			-
BUD								
BUD 46	Tho	Si-N-Darl	S P, 850/400V, 4/5A, 70W, sat<1,6V(2,5A)		17j	TO-220		-
BUD 46 A		Si-N-Darl	=BUD 46: 1000/450V		17j	TO-220		-
BUD 47	Tho	Si-N-Darl	S P, 850/400V, 8/10AA, 100W, sat<1,5A(5A)		17j	TO-220		-
BUD 47 A		Si-N-Darl	=BUD 47: 1000/450V		17j	TO-220		-
BUD 48	Tho	Si-N-Darl	S P, 850/400V, 16/20A, 150W, sat<1,6V(10A)		18j	TO-3P		BUT 51P
BUD 48 A		Si-N-Darl	=BUD 48: 1000/450V		18j	TO-3P		-
BUD 48 DI		Si-N-Darl+Di	=BUD 48: Iso, Damper-Di., 600V, 90W		18c	TO-3P Iso		-
BUD 48 I, AI		Si-N-Darl	=BUD 48(A): Iso, 90W		18c	TO-3P Iso		-
BUD 98	Tho	Si-N-Darl	S P, 850/400V, 32/40A, 250W, sat<1,6V(20A)		18j	TO-3P		-
BUD 98 I		Si-N-Darl	=BUD 98: Iso, 110W		18c	TO-3P Iso		-
BUF….BUH								
BUF 298 F,AF,V,AV	Tho	Si-N	=BUV 298…:		≈67	SOT-227A,B		-
BUF 405	Tho	Si-N	S P, SMPS, 850/450V, 7,5/15A, 80W, sat<2V(5A)		17j	TO-220	BUF 405 A	17j -
BUF 405 A		Si-N	=BUF 405: 1000/450V		17j	TO-220	BUF 405 A	17j -
BUF 410	Tho	Si-N	S P, SMPS, 850/450V, 15/30A, 125W, sat<2V(10A)		18j	TO-3P		-
BUF 410 A		Si-N	=BUF 410: 1000/450V		18j	TO-3P		-
BUF 410 AI		Si-N	=BUF 410A: Iso, 85W		18c	TO-3P Iso		-
BUF 410 I		Si-N	=BUF 410: Iso, 85W		18c	TO-3P Iso		-
BUF 420	Tho	Si-N	S P, SMPS, 850/450V, 30/60A, 200W, sat<2V(20A)		18j	TO-3P		-
BUF 420 A		Si-N	=BUF 420: 1000/450V		18j	TO-3P		-
BUF 420 AI		Si-N	=BUF 420A: Iso, 115W		18c	TO-3P Iso		-
BUF 420 AM		Si-N	=BUF 420A: 200W		23a	TO-3		-
BUF 420 I		Si-N	=BUF 420: Iso, 115W		18c	TO-3P Iso		-
BUF 420 M		Si-N	=BUF 420: 200W		23a	TO-3		-
BUF 460(F)	Tho	Si-N	S P, 850/450V, 80A, 300V, sat<2V(60A)		≈67(EECB)	SOT-227B		-
BUF 460 A,AF		Si-N	=BUF 460(F): 1000/450V		≈67(EECB)	SOT-227B		-
BUF 460 V,AV		Si-N	=BUF 460(F,AF):		≈67(EECB)	SOT-227A		-
BUF 646	Aeg	Si-N	S P, 850/400V, 7A, 80W, 250ns, sat=0,4V(4A)		17j	TO-220	BUF 405 A	17j BUT 12(A), BUT 56(A), BUF 405(A)
BUF 646 A		Si-N	=BUF 646: 1000/450V		17j	TO-220	BUF 405 A	17j BUT 12A, BUT 56A, BUF 405A
BUF 656 B	Aeg	Si-N	S P, 1100/400V, 7A, 70W, 180ns, sat<1,5V(3A)		17j	TO-220	(BUF 405 A)[7]	17j (BUT 12A, BUT 56A, BUF 405A)[7]
BUH 313	Tho	Si-N	CRT-HA, hi-res, 1300/600V, 5/8A, 50W, sat<1,5V(3A)		18c	TO-3P Iso	BU 2508 AF	16c BU 2508AF, 2SC3884…85, 2SC3894…95,++
BUH 315 D		Si-N+Di	=BUH 313: integr. Damper-Diode		18c	TO-3P Iso	(BU 508 DF)	16c BU 2508DF, 2SC3892(A), 2SC4764
BUH 315	Tho	Si-N	CRT-HA, hi-res, 1500/700V, 5/8A, 50W, sat<1,5V(3A)		18c	TO-3P Iso	BU 2508 AF	16c BU 2508AF, 2SC3884A…85A, 2SC3894…95
BUH 315 D		Si-N+Di	=BUH 315: integr. Damper-Diode		18c	TO-3P Iso	(BU 508 DF)	16c BU 2508DF, 2SC3892A, 2SC4764
BUH 417	Tho	Si-N	CRT-HA,hi-res, 1700/700V, 7/12A, 55W, sat<1,5V(4A)		18c	TO-3P Iso	BUH 517	18c BUH 517
BUH 515	Tho	Si-N	CRT-HA,hi-res, 1500/700V, 8/12A, 60W, sat<1,5V(5A)		18c	TO-3P Iso	BU 2508 AF	16c BU 2508AF, 2SC3886A, 2SC3896, 2SC4758
BUH 515 D		Si-N+Di	=BUH 515: integr. Damper-Diode		18c	TO-3P Iso	(BU 508 DF)	16c BU 2508DF, BU 2520DF, 2SC4763
BUH 517	Tho	Si-N	CRT-HA,hi-res, 1700/700V, 8/15A, 60W, sat<1,5V(5A)		18c	TO-3P Iso	BUH 517	18c -
BUH 517 D		Si-N+Di	=BUH 517: integr. Damper-Diode		18c	TO-3P Iso		-
BUH 715	Tho	Si-N	CTV-HA,hi-res,1500/700V, 10/20A, 60W, sat<1,5V(7A)		18c	TO-3P Iso	2SC4924	18c BU 2520AF, BU 2525AF, 2SC4542, 2SC4759
BUH 1015 T	Tho	Si-N	CRT-HA, hi-res, 1500/700V, 16/22A, 160W, sat<1,5V		18j	TO-3P		-
BUH 1215 T	Tho	Si-N	CRT-HA, hi-res, 1500/700V, 19/26A, 200W, sat<1,5V		18j	TO-3P		-
BUK								
BUK 416-100AE,BE	Phi	MOS-N-FET-e	VFET, 100/30V, 310W, 240/220ns(110A) AE: 110/440A, <13mΩ(55A), BE: 100/400A, <16mΩ(55A)		≈67	SOT-227A (SGDauxS)		-
BUK 416-200AE,BE	Phi	MOS-N-FET-e	VFET, 200/30V, 310W, 240/210ns(63A) AE: 63/250A, <35mΩ(32A), BE: 55/220A, <45mΩ(32A)		≈67	SOT-227A (SGDauxS)		-
BUK 416-1000AE,BE		MOS-N-FET-e	VFET, 1000/30V, 310W, 175/220ns(12,2A) AE: 12,2/49A, <0,8Ω(7,5A), BE: 10,9/44A, <1Ω(7,5A)		≈67	SOT-227A (SGDauxS)		-
BUK 417-500AE,BE	Phi	MOS-N-FET-e	VFET, 500/30V, 310W, 110/400ns(32A) AE: 32/128A, <0,13Ω(16A), BE: 28/112A, <0,16Ω(16A)		≈67	SOT-227A (SGDauxS)		-
BUK 426-50A,B	Phi	MOS-N-FET-e	VFET, 50/30V, 30/120A, 45W, 90/290ns(3A) A: <28mΩ(29A), B: <30mΩ(29A)		16c	SOT-199		2SK1298, 2SK1424, 2SK1435, 2SK1666
BUK 426-60A,B	Phi	MOS-N-FET-e	=BUK 426-50…: 60/30V		16c	SOT-199		2SK1298, 2SK1424, 2SK1435, 2SK1666
BUK 426-100A,B	Phi	MOS-N-FET-e	VFET, 100/30V, 45W, 60/215ns(3A) A: 20/80A, <57mΩ(15A), B: 19/76A, <65mΩ(15A)		16c	SOT-199		2SK2008
BUK 426-200A,B	Phi	MOS-N-FET-e	VFET, 200/30V, 45W, 60/195ns(3A) A: 11/44A, <0,16Ω(10A), B: 10/40A, <0,2Ω(10A)		16c	SOT-199		2SK1206, 2SK1225, 2SK1328, 2SK1831…32++

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BUK 426-800A,B	Phi	MOS-N-FET-e	VFET, 800/30V, 45W, 35/170ns(2,3A) A: 2,4/10A, <3Ω(1,5A), B: 2,1/8,4A, <4Ω(1,5A)		16c	SOT-199			2SK1683
BUK 426-1000A,B	Phi	MOS-N-FET-e	VFET, 1000/30V, 45W, 35/170ns(2,3A) A: 2,1/8,4A, <4Ω(1,5A), B: 1,9/8A, <5Ω(1,5A)		16c	SOT-199			BUK 428-1000, 2SK1770
BUK 427-400A,B		MOS-N-FET-e	VFET, 400/30V, 45W, 80/275ns(2,8A) A: 6,9/28A, <0,4Ω(6,5A), B: 6,2/25A, <0,5Ω(6,5A)		16c	SOT-199			2SK1206, 2SK1225, 2SK1328, 2SK1831…32++
BUK 427-450B	Phi	MOS-N-FET-e	VFET, 450/30V, 5,6A, 45W, <0,6Ω(6,5A), 80/275ns		16c	SOT-199			2SK1206, 2SK1225, 2SK1328, 2SK1831…32++
BUK 427-500A,B	Phi	MOS-N-FET-e	VFET, 500/30V, 45W, 80/275ns(2,8A) A: 5,6/22A, <0,6Ω(6,5A), B: 4,8/19A, <0,8Ω(6,5A)		16c	SOT-199			2SK1206, 2SK1329, 2SK1523, 2SK1832,++
BUK 427-600A,B	Phi	MOS-N-FET-e	VFET, 600/30V, 45W, 80/275ns(2,8A) A: 4,3/17A, <1Ω(6,5A), B: 3,9/16A, <1,2Ω(6,5A)		16c	SOT-199			BUK 727-600, 2SK1463, 2SK1684, 2SK1859
BUK 428-500A,B	Phi	MOS-N-FET-e	VFET, 500/30V, 45W, 120/410ns(2,9A) A: 6,8/27A, <0,4Ω(8A), B: 6,1/24A, <0,5Ω(8A)		16c	SOT-199			2SK1206, 2SK1523, 2SK1696, 2SK1832
BUK 428-800A,B	Phi	MOS-N-FET-e	VFET, 800/30V, 45W, 160/450ns(2,6A) A: 3,4/14A, <1,5Ω(4A), B: 3/12A, <2Ω(4A)		16c	SOT-199			2SK809A, 2SK1463, 2SK1684, 2SK1859
BUK 428-1000A,B	Phi	MOS-N-FET-e	VFET, 1000/30V, 45W, 160/450ns(2,5A) A: 2,9/12A, <2Ω(3,5A), B: 2,6/10A, <2,6Ω(3,5A)		16c	SOT-199			BUK 426-1000, 2SK1770
BUK 436-50A,B	Phi	MOS-N-FET-e	=BUK 426-50A,B: A=50/200A, B=46/184A, 125W		18p	TO-3P			BUZ 346, 2SK1297, 2SK1379, 2SK1514
BUK 436-60A,B	Phi	MOS-N-FET-e	=BUK 426-60A,B: A=50/200A, B=46/184A, 125W		18p	TO-3P			2SK1297, 2SK1379, 2SK1514, 2SK2096
BUK 436-100A,B	Phi	MOS-N-FET-e	=BUK 426-100A,B: A=33/132A, B=31/124A, 125W		18p	TO-3P			BUZ 345, 2SK850, 2SK906, 2SK1429, ++
BUK 436-200A,B	Phi	MOS-N-FET-e	=BUK 426-200A,B: A=19/76A, B=17/68A, 125W		18p	TO-3P			BUZ 350, 2SK851, 2SK623, 2SK901, 2SK1491
BUK 436-800A,B	Phi	MOS-N-FET-e	=BUK 426-800A,B: A=4/16A, B=3,5/14A, 125W		18p	TO-3P			BUZ 355…356, 2SK727, 2SK793, 2SK1794,++
BUK 436-1000A,B	Phi	MOS-N-FET-e	=BUK 426-1000A,B: A=3,5/14A, B=3,1/12A, 125W		18p	TO-3P			BUZ 312, 2SK696, 2SK1359, 2SK1773,++
BUK 437-400A,B	Phi	MOS-N-FET-e	=BUK 427-400A,B: A=14/56A, B=12/48A, 180W		18p	TO-3P			-
BUK 437-450B	Phi	MOS-N-FET-e	=BUK 427-450B: 11A, 180W		18p	TO-3P			-
BUK 437-500A,B	Phi	MOS-N-FET-e	=BUK 427-500A,B: A=11/44A, B=10/40A, 180W		18p	TO-3P			-
BUK 437-600A,B	Phi	MOS-N-FET-e	=BUK 427-600A,B: A=9/36A, B=7,8/31A, 180W		18p	TO-3P			-
BUK 438-500A,B	Phi	MOS-N-FET-e	=BUK 428-500A,B: A=15/60A, B=13,5/54A, 220W		18p	TO-3P			2SK1678
BUK 438-800A,B	Phi	MOS-N-FET-e	=BUK 428-800A,B: A=7,6/30A, B=6,6/26A, 220W		18p	TO-3P			-
BUK 438-1000A,B	Phi	MOS-N-FET-e	=BUK 428A,B: A=6,5/26A, B=5,7/23A, 220W		18p	TO-3P			-
BUK 439-60A	Phi	MOS-N-FET-e	VFET, 60/30V, 50/400A, 230W, <0,13Ω(50A), 75/90ns		18p	TO-3P			BUK 539-60
BUK 441-60A,B	Phi	MOS-N-FET-e	VFET, 60/30V, 20W, 19/25ns(3A) A: 5/20A, <0,4Ω(4A), B: 4,8/19A, <0,5Ω(4A)		17c	SOT-186			BUK 541-60, 2SK1260, 2SK1265
BUK 441-100A,B	Phi	MOS-N-FET-e	VFET, 100/30V, 20W, 19/20ns(3A) A: 3/13A, <0,85Ω(2,5A), B: 3/11A, <1,1Ω(2,5A)		17c	SOT-186			BUK 541-60, 2SK1264…65
BUK 442-50A,B	Phi	MOS-N-FET-e	VFET, 50/30V, 22W, 33/60ns(3A) A: 10A, <0,13Ω(8,5A), B: 9,2A, <0,15Ω(8,5A)		17c	SOT-186			BUK 543-50, BUZ71(A)F, 2SK1093, 2SK1974+
BUK 442-60A,B	Phi	MOS-N-FET-e	=BUK 442-50A,B: A=10/40A, B=9,2/37A		17c	SOT-186			BUK 545-100, 2SK1093, 2SK1344, 2SK1974++
BUK 442-100A,B	Phi	MOS-N-FET-e	VFET, 100/30V, 22W, 34/50ns(3A) A: 6,6/26A, <0,25Ω(5,5A), B: 6,1/24A, <0,3Ω(5,5A)		17c	SOT-186			BUK443-100, BUZ72(A)F, 2SK1261, 2SK1556+
BUK 443-50A,B	Phi	MOS-N-FET-e	VFET, 50/30V, 25W, 45/115ns(3A) A: 13/52A, <0,08Ω(9A), B: 12A, <0,1Ω(9A)		17c	SOT-186			2SK1094, 2SK1419
BUK 443-60A,B	Phi	MOS-N-FET-e	=BUK 443-50A,B: 60/30V		17c	SOT-186			2SK1094, 2SK1419
BUK 443-100A,B	Phi	MOS-N-FET-e	VFET, 100/30V, 25W, 35/100ns(2,9A) A: 9/36A, <0,16Ω(5A), B: 8/32A, <0,2Ω(5A)		17c	SOT-186			BUK543-100, BUZ72(A)F, 2SK1261, 2SK1430+
BUK 444-200A,B	Phi	MOS-N-FET-e	VFET, 200/30V, 25W, 57/120ns(2,9A) A: 5,3/21A, <0,4Ω(3,5A), B: 4,7/19A, <0,5Ω(3,5A)		17c	SOT-186			BUK 445-200, 2SK1478, 2SK1568…69, ++
BUK 444-400A,B	Phi	MOS-N-FET-e	VFET, 400/30V, 25W, 55/80ns(2,5A) A: 2,7/11A, <1,5Ω(1,5A), B: 2,4/9,6A, <1,8Ω(1,5A)		17c	SOT-186			BUK 445-450, 2SK503, 2SK1833, 2SB1862,++
BUK 444-450B	Phi	MOS-N-FET-e	VFET, 450/30V, 2,1A, 25W, <2,3Ω(1,2A), 55/80ns		17c	SOT-186			BUK 445-450, 2SK1833, 2SK1862…63
BUK 444-500A,B	Phi	MOS-N-FET-e	VFET, 500/30V, 25W, 55/80ns(2,3A) A: 2,1/8,4A, <2,3Ω(1,2A), B: 1,9/7,6A, <2,8Ω(1,2A)		17c	SOT-186			BUK 445-500, 2SK1758, 2SK1833…34
BUK 444-600A,B	Phi	MOS-N-FET-e	VFET, 600/30V, 25W, 55/80ns(2,1A) A: 1,6/6,4A, <4Ω(1,2A), B: 1,5/6A, <4,5Ω(1,2A)		17c	SOT-186			BUK 445-600, 2SK1611, 2SK1758, 2SK1834++
BUK 444-800A,B	Phi	MOS-N-FET-e	VFET, 800/30V, 25W, 40/80ns(1,9A) A: 1,4/5,6A, <6Ω(1A), B: 1,2/4,8A, <8Ω(1A)		17c	SOT-186	BUK 444-800	17c	BUK 446-1000, 2SK808(A), 2SK1834
BUK 445-50A,B	Phi	MOS-N-FET-e	VFET, 50/30V, 30W, 85/225ns(3A) A: 21/84A, <38mΩ(20A), B: 20/80A, <45mΩ(20A)		17c	SOT-186			BUK 545-50, BUZ 11F, 2SK1214, 2SK1420,++
BUK 445-60A,B	Phi	MOS-N-FET-e	=BUK 445-50A,B: 60/30V		17c	SOT-186			2SK943, 2SK1095, 2SK1214, 2SK1420,++
BUK 445-100A,B	Phi	MOS-N-FET-e	VFET, 100V, 30W, 40/150ns(3A) A: 14/56A, <80mΩ(13A), B: 12/48A, <0,1Ω(13A)		17c	SOT-186			2SK1034, 2SK1350, 2SK1431, 2SK1558,++
BUK 445-200A,B	Phi	MOS-N-FET-e	VFET, 200/30V, 30W, 53/120ns(3A) A: 7,6/30A, <0,23Ω(7A), B: 7/28A, <0,28Ω(7A)		17c	SOT-186			BUK 545-200, 2SK1478, 2SK1568…69,++
BUK 445-400A,B	Phi	MOS-N-FET-e	VFET, 400/30V, 30W, 35/165ns(2,7A) A: 4/16A, <0,8Ω(2,5A), B: 3,6/14A, <1Ω(2,5A)		17c	SOT-186			2SK1231, 2SK1351, 2SK1377, 2SK1626,++
BUK 445-450B	Phi	MOS-N-FET-e	VFET, 450/30V, 3,1A, 30W, <1,3Ω(2,5A), 35/160ns		17c	SOT-186			2SK1231, 2SK1351, 2SK1377, 2SK1626,++
BUK 445-500A,B	Phi	MOS-N-FET-e	VFET, 500/30V, 30W, 55/140ns(2,6A) A: 3,1/12A, <1,3Ω(2,5A), B: 2,9/12A, <1,5Ω(2,5A)		17c	SOT-186			2SK1572, 2SK1767, 2SK2144
BUK 445-600A,B	Phi	MOS-N-FET-e	VFET, 600/30V, 30W, 55/140ns(2,6A) A: 2,5/10A, <2Ω(2,5A), B: 2,2/8,8A, <2,5Ω(2,5A)		17c	SOT-186			BUK 446-800, 2SK1611, 2SK1758, 2SK1834
BUK 446-800A,B	Phi	MOS-N-FET-e	VFET, 800/30V, 30W, 35/170na(2,3A) A: 2/8A, <3Ω(1,5A), B: 1,7/6,8A, <4Ω(1,5A)		17c	SOT-186			2SK1275, 2SK1459, 2SK1611, 2SK1834,++
BUK 446-1000A,B	Phi	MOS-N-FET-e	VFET, 1000V, 30W, 35/170ns(2,3A) A: 1,7/6,8A, <4Ω(1,5A), B: 1,5/6A, <5Ω(1,5A)		17c	SOT-186			-
BUK 451-60A,B	Phi	MOS-N-FET-e	=BUK 441-50A,B: 5/20A, 40W		17p	TO-220			IRF 511, IRF 513, 2SK346, 2SK463, ++
BUK 451-100A,B	Phi	MOS-N-FET-e	=BUK 441-100A,B: 3/12A, 40W		17p	TO-220			IRF 612, IRF 613, 2SK923
BUK 452-50A,B	Phi	MOS-N-FET-e	=BUK 442-50A,B: A=15/60A, B=14/56A, 60W		17p	TO-220			IRF 531, 2SK673, 2SK971, 2SK1416
BUK 452-60A,B	Phi	MOS-N-FET-e	=BUK 442-60A,B: A=15/60A, B=14/56A, 60W		17p	TO-220			IRF 531, 2SK673, 2SK971, 2SK1416
BUK 452-100A,B	Phi	MOS-N-FET-e	=BUK 442-100A,B: A=11/44A, B=10/40A, 60W		17p	TO-220			BUZ 20, BUZ 72, 2SK918, 2SK921, 2SK1427+
BUK 453-50A,B	Phi	MOS-N-FET-e	=BUK 443-50A,B: A=22/88A, B=20/80A, 75W		17p	TO-220			BUZ 10, BUZ 21, 2SK600, 2SK674, 2SK972++
BUK 453-60A,B	Phi	MOS-N-FET-e	=BUK 443-60A,B: A=22/88A, B=20/80A, 75W		17p	TO-220			BUZ 21, 2SK600, 2SK674, 2SK972, 2SK1417+
BUK 453-100A,B	Phi	MOS-N-FET-e	=BUK 443-100A,B: A=14/56A, B=13/52A, 75W		17p	TO-220			BUZ 21…22, 2SK919, 2SK929, 2SK1301, ++
BUK 453-500A,B	Phi	MOS-N-FET-e	VFET, 500/30V, 75W, 40/50ns(1,8A) A: 1,7/6,8A, <6Ω(0,6A), B: 1,6/6,4A, <7Ω(0,6A)		17p	TO-220			BUZ 74, IRF 820, IRF 822, 2SK822, 2SK892
BUK 454-200A,B	Phi	MOS-N-FET-e	=BUK 444-200A,B: A=9,2/36A, B=8,2/33A, 75W		17p	TO-220			BUZ 31…32, 2SK459, 2SK477, 2SK1319, ++
BUK 454-400A,B	Phi	MOS-N-FET-e	=BUK 444-400A,B: A=4,6/18A, B=4,2/17A, 75W		17p	TO-220			BUZ 41…42, BUZ 60, 2SK552…53, 2SK1751+
BUK 454-450B	Phi	MOS-N-FET-e	=BUK 444-450B: 3,7A, 75W		17p	TO-220			BUZ 41…42, 2SK552…53, 2SK893, 2SK1751+
BUK 454-500A,B	Phi	MOS-N-FET-e	=BUK 444-500A,B: A=3,7/15A, B=3,3/13A, 75W		17p	TO-220			BUZ 41…42, 2SK553, 2SK893, 2SK1751, ++
BUK 454-600A,B	Phi	MOS-N-FET-e	=BUK 440-600A,B: A=2,8/11A, B=2,6/11A, 75W		17p	TO-220			2SK513, 2SK791…792, 2SK1600…1601, ++
BUK 454-800A,B	Phi	MOS-N-FET-e	=BUK 444-800A,B: A=2,4/9,5A, B=2/8A, 75W		17p	TO-220			BUZ 50, BUZ 80, 2SK1199, 2SK1323, ++
BUK 455-50A,B	Phi	MOS-N-FET-e	=BUK 445-50A,B: A=41/164A, B=38/152A, 125W		17p	TO-220			-
BUK 455-60A,B	Phi	MOS-N-FET-e	=BUK 445-60A,B: A=41/164A, B=38/152A, 125W		17p	TO-220			-
BUK 455-100A,B	Phi	MOS-N-FET-e	=BUK 445-100A,B: A=26/104A, B=23/92A, 125W		17p	TO-220			-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BUK 455-200A,B	Phi	MOS-N-FET-e	=BUK 445-200A,B: A=14/56A, B=13/52A, 125W		17p	TO-220			-
BUK 455-400A,B	Phi	MOS-N-FET-e	=BUK 445-400A,B: A=7,3/29A, B=6,5/26A, 100W		17p	TO-220			-
BUK 455-450B	Phi	MOS-N-FET-e	=BUK 445-450B: 5,7A, 100W		17p	TO-220			-
BUK 455-500A,B	Phi	MOS-N-FET-e	=BUK 445-500A,B: A=5,7/23A, B=5,3/21A, 100W		17p	TO-220	BUK 455/600A,B	17p	-
BUK 455-600A,B	Phi	MOS-N-FET-e	=BUK 445-600A,B: A=4,5/18A, B=4/16A, 100W		17p	TO-220	BUK 455/600A,B	17p	-
BUK 456-50A,B	Phi	MOS-N-FET-e	VFET, 50/30V, 150W, 90/290ns(3A) A: 52/208A, <28mΩ(29A), B: 51/200A, <30mΩ(29A)		17p	TO-220			-
BUK 456-60A,B	Phi	MOS-N-FET-e	=BUK 456-50A,B: 60/30V		17p	TO-220			-
BUK 456-100A,B	Phi	MOS-N-FET-e	VFET, 100/30V, 150W, 60/215ns(3A) A: 34/136A, <57mΩ(15A), B: 32/128A, <65mΩ(15A)		17p	TO-220			-
BUK 456-200A,B	Phi	MOS-N-FET-e	VFET, 200/30V, 150W, 60/195ns(3A) A: 19/76A, <0,16Ω(10A), B: 17/68A, <0,2Ω(10A)		17p	TO-220			-
BUK 456-800A,B	Phi	MOS-N-FET-e	VFET, 800/30V, 125W, 35/170ns(2,3A) A: 4/16A, <3Ω(1,5A), B: 3,5/14A, <4Ω(1,5A)		17p	TO-220			-
BUK 456-1000A,B	Phi	MOS-N-FET-e	VFET, 1000/30V, 125W, 35/170ns(2,3A) A: 3,5/14A, <4Ω(1,5A), B: 3,1/12A, <5Ω(1,5A)		17p	TO-220			-
BUK 457-400A,B	Phi	MOS-N-FET-e	VFET, 400/30V, 150W, 80/275ns(2,8A) A: 13/52A, <0,4Ω(6,5A), B: 11/44A, <0,5Ω(6,5A)		17p	TO-220			-
BUK 457-450B	Phi	MOS-N-FET-e	VFET, 450/30V, 10A, 150W, <0,6Ω(6,5A), 80/275ns		17p	TO-220			-
BUK 457-500A,B	Phi	MOS-N-FET-e	VFET, 500/30V, 150W, 80/275ns(2,8A) A: 10/40A, <0,6Ω(6,5A), B: 9/36A, <0,8Ω(6,5A)		17p	TO-220			-
BUK 457-600A,B	Phi	MOS-N-FET-e	VFET, 600/30V, 150W, 80/275ns(2,8A) A: 8/32A, <1Ω(6,5A), B: 7,1/28A, <1,2Ω(6,5A)		17p	TO-220			-
BUK 471-....	Phi	MOS-N-FET-e	=BUK 441-...:		17c	TO-220Iso			›BUK 441-...
BUK 472-....	Phi	MOS-N-FET-e	=BUK 442-...:		17c	TO-220Iso			›BUK 442-...
BUK 473-....	Phi	MOS-N-FET-e	=BUK 443-...:		17c	TO-220Iso			›BUK 443-...
BUK 474-....	Phi	MOS-N-FET-e	=BUK 444-...:		17c	TO-220Iso	›BUK 444-...		›BUK 444-...
BUK 475-....	Phi	MOS-N-FET-e	=BUK 445-...:		17c	TO-220Iso			›BUK 445-...
BUK 476-....	Phi	MOS-N-FET-e	=BUK 446-...:		17c	TO-220Iso			›BUK 446-...
BUK 539-60A	Phi	MOS-N-FET-e	VFET, LogL, 60/15V, 50/400A, 230W, <15mΩ(50A)		18p	TO-3P			-
BUK 541-60A,B	Phi	MOS-N-FET-e	VFET, LogL, 60/15V, 20W, 36/40ns(3A) A: 5/20A, <0,4Ω(4A), B: 4,8/20A, <0,5Ω(4A)		17c	SOT-186			BUK 542-100,BUK 554-200, 2SK1260
BUK 541-100A,B	Phi	MOS-N-FET-e	VFET, LogL, 100/15V, 3/12A, 20W, 36/30ns(3A) A: <0.85Ω(2,5A), B: <1,1Ω(2,5A)		17c	SOT-186			BUK 542-200, 2SK1260
BUK 542-50A,B	Phi	MOS-N-FET-e	VFET, LogL, 50/15V, 22W, 72/95ns(3A) A: 9,2/37A, <0,15Ω(8,5A), B: 8,4/33A, <0,18Ω(8,5A)		17c	SOT-186			BUK 543-50, 2SK1033, 2SK1256, 2SK1344,++
BUK 542-60A,B	Phi	MOS-N-FET-e	=BUK 542-50A,B: 60/15V		17c	SOT-186			BUK 543-60, 2SK1033, 2SK1256, 2SK1344,++
BUK 542-100A,B	Phi	MOS-N-FET-e	VFET, LogL, 100/15V, 22W, 57/80ns(3A) A: 6,3/25A, <0,28Ω(5,5A), B: 5,6/22A, <0,35Ω(5,5A)		17c	SOT-186			BUK 543-100, 2SK1261, 2SK1305, 2SK1556++
BUK 543-50A,B	Phi	MOS-N-FET-e	VFET, LogL, 50/15V, 25W, 115/145ns(3A) A: 13/52A, <85mΩ(10A), B: 12/48A, <0,1Ω(10A)		17c	SOT-186			BUK 545-100, 2SK1033, 2SK1256, 2SK1344++
BUK 543-60A,B	Phi	MOS-N-FET-e	=BUK 543-50A,B: 60/15V		17c	SOT-186			BUK 545-100, 2SK1033, 2SK1256, 2SK1344
BUK 543-100A,B	Phi	MOS-N-FET-e	VFET, LogL, 100/15V, 25W, 55/130ns(3A) A: 8,3/33A, <0,18Ω(5A), B: 7,5/30A, <0,22Ω(5A)		17c	SOT-186			BUK 545-100, 2SK1035, 2SK1261, 2SK1305++
BUK 545-50A,B	Phi	MOS-N-FET-e	VFET, LogL, 50/15V, 30W, 145/270ns(3A) A: 20/80A, <42mΩ(20A), B: 18/72A, <55mΩ(20A)		17c	SOT-186			2SK943, 2SK1095, 2SK1345...46, 2SK1951,++
BUK 545-60A,B	Phi	MOS-N-FET-e	=BUK 545-50A,B: 60/15V		17c	SOT-186			2SK943, 2SK1095, 2SK1345...46, 2SK1951,++
BUK 545-100A,B	Phi	MOS-N-FET-e	VFET, LogL, 100/15V, 30W, 90/215ns(3A) A: 13/52A, <85mΩ(13A), B: 12/48A, <0,11Ω(13A)		17c	SOT-186			2SK1034...35, 2SK1306, 2SK1558
BUK 545-200A,B	Phi	MOS-N-FET-e	VFET, LogL, 200/15V, 30W, 70/180ns(3A) A: 7,6/30A, <0,23Ω(7A), B: 7/28A, <0,28Ω(7A)		17c	SOT-186			2SK2160...61
BUK 551-100A,B	Phi	MOS-N-FET-e	=BUK 541-100A,B: 40W		17p	TO-220			-
BUK 552-50A,B	Phi	MOS-N-FET-e	=BUK 542-50A;B: A=14/56A, B=13/56A, 60W		17p	TO-220			2SK971, 2SK1555
BUK 552-60A,B	Phi	MOS-N-FET-e	=BUK 542-60A,B: A=14/56A, B=13/52A, 60W		17p	TO-220			2SK971, 2SK1300...01, 2SK1559, 2SK1561,++
BUK 552-100A,B	Phi	MOS-N-FET-e	=BUK 542-100A,B: A=10/40V, B=8,5/34A, 60W		17p	TO-220			2SK1300...01, 2SK1559, 2SK1561
BUK 553-50A,B	Phi	MOS-N-FET-e	=BUK 543-50A,B: A=21/84A, B=20/80A, 75W		17p	TO-220			2SK972, 2SK1115...16, 2SK1302, 2SK1347,++
BUK 553-60A,B	Phi	MOS-N-FET-e	=BUK 543-60A,B: A=21/84A, B=20/80A, 75W		17p	TO-220			2SK972, 2SK1115...16, 2SK1302, 2SK1347,++
BUK 553-100A,B	Phi	MOS-N-FET-e	=BUK 543-100A,B: A=13/52A, B=12/48A, 75W		17p	TO-220			2SK1301, 2SK1559, 2SK1561
BUK 554-200A,B	Phi	MOS-N-FET-e	VFET, LogL, 200/15V, 90W, 91/170ns(2,9A) A: 9,2/36A, <0,4Ω(3,5A), B: 8,2/33A, <0,5Ω(3,5A)		17p	TO-220			BUK 555-200
BUK 555-50A,B	Phi	MOS-N-FET-e	=BUK 545-50A,B: A=39/156A, B=35/140A, 125W		17p	TO-220			-
BUK 555-60A,B	Phi	MOS-N-FET-e	=BUK 545-60A,B: A=39/156A, B=35/140A, 125W		17p	TO-220			-
BUK 555-100A,B	Phi	MOS-N-FET-e	=BUK 545-100A,B: A=25/100A, B=22/88A, 125W		17p	TO-220			-
BUK 555-200A,B	Phi	MOS-N-FET-e	=BUK 545-200A,B: A=14/56A; B=13/52A, 125W		17p	TO-220			-
BUK 556-60A	Phi	MOS-N-FET-e	VFET, LogL, 60/15V, 50/200A, 150W, <26mΩ(25A)		17p	TO-220			2SK1542
BUK 571-....	Phi	MOS-N-FET-e	=BUK 541-...		17c	TO-220Iso			›BUK 541-...
BUK 572-....	Phi	MOS-N-FET-e	=BUK 542-...		17c	TO-220Iso			›BUK 542-...
BUK 573-....	Phi	MOS-N-FET-e	=BUK 543-...		17c	TO-220Iso			›BUK 543-...
BUK 575-....	Phi	MOS-N-FET-e	=BUK 545-...		17c	TO-220Iso			›BUK 545-...
BUK 617-500AE,BE	Phi	MOS-N-FET-e	FREDFET, 500/30V, 310W, 110/400ns(29A) A: 29/116A, <0,15Ω(16A), B: 27/108A, <0,18Ω(16A)		=67	SOT-227A (SGDauxS)			-
BUK 627-400A,B	Phi	MOS-N-FET-e	FREDFET, 400V, 45W, 80/275ns(2,8A) A: 6,9A, <0,5Ω(6,5A), B: 6,2A, <0,6Ω(6,5A)		16c	SOT-199			-
BUK 627-450B	Phi	MOS-N-FET-e	FREDFET, 450/30V, 5,6A, 45W, <0,65Ω, 80/275ns		16c	SOT-199			-
BUK 627-500A,B,C	Phi	MOS-N-FET-e	FREDFET, 500/30V, 45W, 80/275ns(2,8A), A: 5,6/22A, <0,65Ω, B: 4,8/19A, <0,8Ω, C: 4,5/-A, <0,9Ω(6,5A)		16c	SOT-199			-
BUK 627-600A,B,C	Phi	MOS-N-FET-e	FREDFET, 600/30V, 45W, 80/275ns(2,8A), A: 4,3/-A, <0,1Ω, B: 3,9/-A, <1,2Ω, C: 3,5/-A, <1,4Ω(6,5A)		16c	SOT-199			-
BUK 637-400A,B	Phi	MOS-N-FET-e	=BUK 627-400A,B: A=14/56A, B=12/48A, 180W		18p	TO-3P			BUK 638-500
BUK 637-450B	Phi	MOS-N-FET-e	=BUK 627-450B: 11A, 180W		18p	TO-3P			BUK 638-500
BUK 637-500A,B,C	Phi	MOS-N-FET-e	=BUK 627-500...: A=11/44A, B=10/40A, C=9,5/-A, 180W		18p	TO-3P			BUK 638-500
BUK 637-600A,B,C	Phi	MOS-N-FET-e	=BUK 726-600...: A=9/-A, B=7,8/-A, C=7/-A, 180W		18p	TO-3P			BUK 638-800
BUK 638-500A,B	Phi	MOS-N-FET-e	FREDFET, 500/30V, 220W, 120/410ns(2,8A) A: 14,6/58A, <0,48Ω(8A), B: 13/52A, <0,6Ω(8A)		18p	TO-3P			-
BUK 638-800A,B	Phi	MOS-N-FET-e	FREDFET, 800/30V, 220W, 160/450ns(2,5A) A: 7,3/29A, <1,8Ω(4A), B: 6,3/25A, <2,4Ω(4A)		18p	TO-3P			-
BUK 638-1000A,B	Phi	MOS-N-FET-e	FREDFET, 1000/30V, 220W, 160/450ns(2,5A) A: 6,2/25A, <2,4Ω(3,5A), B: 5,6/22A, <3Ω(3,5A)		18p	TO-3P			-
BUK 655-450B	Phi	MOS-N-FET-e	FREDFET, 450V, 5,7/23A, 100W, <1,3Ω(2,5A),55/140ns		17p	TO-220			(BUZ 215)[7]
BUK 655-500A,B,C	Phi	MOS-N-FET-e	FREDFET, 500/30V, 100W, 55/140ns(2,6A), A: 5,7/23A <1,3Ω(2,5A), B:5,3/21A, <1,5Ω(2,5A), C:5/-A, <1,7Ω		17p	TO-220			-
BUK 657-400A,B	Phi	MOS-N-FET-e	=BUK 627A,B: A=13/52A, B=11/44A, 150W		17p	TO-220			-
BUK 657-450B	Phi	MOS-N-FET-e	=BUK 627-450B: 10/-A, 150W		17p	TO-220			-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BUK 657-500A,B,C	Phi	MOS-N-FET-e	=BUK 627...: A=10/40A, B=9/36A, C=8,5/-A, 150W		17p	TO-220			-
BUK 657-600A,B,C	Phi	MOS-N-FET-e	=BUK 627-600...: A=8/-A, B=7,1/-A, C=6,5/-A, 150W		17p	TO-220			-
BUK 793-60A	Phi	MOS-N-FET-e	Sensor-FET, 60/30V, 20/80A, 75W, <0,1Ω(10A)		17/5Pin	TO-220/5			-
BUK 795-60A	Phi	MOS-N-FET-e	Sensor-FET, 60/30V, 38/152A, 125W, <45mΩ(20A)		17/5Pin	TO-220/5			-
BUK 993-60A	Phi	MOS-N-FET-e	Sensor-FET, LogL, 60/15V, 18/72A, 75W, <0,12Ω(10A)		17/5Pin	TO-220/5			-
BUK 995-60A	Sie	MOS-N-FET-e	Sensor-FET, LogL, 60/15V, 34/136A, 125W,<55mΩ(20A)		17/5Pin	TO-220/5			-
BUL 26	Tho	Si-N	El. Light Ballast, 600/300V, 4A, 60W, <-/3µs		17j	TO-220	BUT 11 A	17j	BUT 11(A), BUV 46(A), MJE 13070, 2SC3830
BUL 38 D	Tho	Si-N	El. Light Ballast, 800/400V, 5A, 70W, <-/1,9µs		17j	TO-220	BUT 11 A	17j	BUT 11(A), BUT 46, BUV 46(A), 2SC3047
BUL 48	Tho	Si-N	SMPS,FLT, 800/400V, 7/11A, 75W, <-/2,1µs		17j	TO-220	BUT 12 A	17j	BUT 12(A), BUT 54, BUT 76(A), BUV 56(A)
BUL 57	Tho	Si-N	El. Light Ballast, 700/400V, 7A, 75W, <-/2,71µs		17j	TO-220	BUT 12 A	17j	BUF 405(A), BUL 48, BUT 12(A), BUT 56(A)
BUL 57 PI		Si-N	=BUL 57: Iso, 35W		17c	TO-220 Iso	BUT 12 AF	17c	BU 307F, BUT 12(A), BUT 22BF,CF
BUL 67	Tho	Si-N	El. Light Ballast, 700/400V, 8A, 80W, <-/3,38µs		17j	TO-220	BUF 405 A	17j	BUF 405(A), BUL 48, BUT 12(A), BUT 56(A)
BUL 87	Tho	Si-N	El. Light Ballast, 700/400V, 10A, 90W, <-/5,05µs		17j	TO-220			BUT 76(A), BUV 56(A), BUV 66(A)
BUL 213	Tho	Si-N	El. Light Ballast, 1300/600V, 3A, 60W, <-/6,35µs		17j	TO-220			BU 505, 2SC4021
BUL 216	Tho	Si-N	El. Light Ballast, 1600/800V, 4A, 70W, <-/4,02µs		17j	TO-220			-
BUL 381	Tho	Si-N	El. Light Ballast, 800/400V, 5A, 70W, <-/2,72µs		17j	TO-220	BUT 11 A	17j	BUT 11(A), BUT 46, BUV 46(A), 2SC3047
BUL 382	Tho	Si-N	El. Light Ballast, 800/400V, 5A, 70W, <-/2,72µs		17j	TO-220	BUT 11 A	17j	BUT 11(A), BUT 46, BUV 46(A), 2SC3047
BUL 410	Tho	Si-N	SMPS,FLT, 1000/450V, 7/11A, 75W, <-/2,11µs		17j	TO-220	BUT 12 A	17j	BUT 12A, BUT 56A, BUV 56A, BUV 66A
BUL 416	Tho	Si-N	El. Light Ballast, 1600/800V, 6A, 85W, <-/2,95µs		17j	TO-220			-
BUL 510	Tho	Si-N	SMPS,FLT, 1000/450V, 8/12A, 75W, <-/3,55µs		17j	TO-220	BUT 12 A	17j	BUT 12A, BUT 56A, BUV 56A, BUV 66A
BUL 810	Tho	Si-N	El. Light Ballast, 1000/450V, 15A, 125W, <-/2,41µs		18j	TO-3P	BUW 13 A	18j	BUV 48A, BUW 13A, BUW 133A, 2SC3552
BULD 85	Tix	Si-N+Di	S-L, HF Electronic Ballast, 600V, 8A, 85W		17c	TO-220Iso			-
BULD 125	Tix	Si-N+Di	S-L, HF Electronic Ballast, 600V, 12A, 125W		17c	TO-220Iso			-
BULK 26	Tho	Si-N	=BUL 26: 50W		=14	SOT-82	(BUT 11 A)[4]	17j	-
BULK 38 D	Tho	Si-N	=BUL 38D: 60W		=14	SOT-82	(BUT 11 A)[4]	17j	-
BULK 381	Tho	Si-N	=BUL 381: 60W		=14	SOT-82	(BUT 11 A)[4]	17j	-
BULK 382	Tho	Si-N	=BUL 382: 60W		=14	SOT-82	(BUT 11 A)[4]	17j	-
BUP									
BUP 22	Phi	Si-N	S P, 550/300V, 8/20A, 125W, 500/1350ns		18j	TO-3P			BUV 47(A), BUW 12(A), 2SC3089, 2SC3449++
BUP 22 A		Si-N	=BUP 22: 650/350V		18j	TO-3P			BUV 47(A), BUW 12(A), 2SC3089, 2SC3449++
BUP 22 B		Si-N	=BUP 22: 750/400V		18j	TO-3P			BUV 47(A), BUW 12(A), 2SC3089, 2SC3449++
BUP 22 BF		Si-N	=BUP 22B: Iso		18c	SOT-199			BUV47(A)FI, BUW12(A)F, 2SC4301, 2SC4429
BUP 22 C		Si-N	=BUP 22: 850/450V		18j	TO-3P			BUV 47(A), BUW 12(A), 2SC3461, 2SC3536
BUP 22 CF		Si-N	=BUP 22C: Iso		18c	SOT-199			BUV47(A)FI, BUW12(A)F, 2SC4301, 2SC4429
BUP 23	Phi	Si-N	S P, 550/300, 15/30A, 175W, 700/2270ns		18j	TO-3P			BUV 48(A), BUW 13(A), BUX 98AP, 2SC3988
BUP 23 A		Si-N	=BUP 23: 650/350V		18j	TO-3P			BUV 48(A), BUW 13(A), BUX 98AP, 2SC3988
BUP 23 B		Si-N	=BUP 23: 750/400V		18j	TO-3P			BUV 48(A), BUW 13(A), BUX 98AP, 2SC3988
BUP 23 BF		Si-N	=BUP 23B: Iso		18c	SOT-199			BUV 48(A)FI, BUW 13(A)F, BUX 98APl
BUP 23 C		Si-N	=BUP 23: 850/450V		18j	TO-3P			BUV 48(A), BUW 13(A), BUX 98AP
BUP 23 CF		Si-N	=BUP 23C: Iso		18c	SOT-199			BUV 48(A), BUW 13(A), BUX 98APl
BUP 101	Sie	MOS-N-FET-e	Ring Emitter Trans., 1000V, 15A, 90W(Tc=60°)		18c	TO-3P			-
BUP 200	Sie	MOS-N-IGBT	Iso-Gate bipolar Trans., 1200/20V, 3,5/5A, 50W		17(GCE)	TO-220			-
BUP 202	Sie	MOS-N-IGBT	Iso-Gate bipolar Trans., 1000/20V, 12/16A, 100W		17(GCE)	TO-220			-
BUP 203	Sie	MOS-N-IGBT	Iso-Gate bipolar Trans., 1000/20V, 21/30A, 165W		17(GCE)	TO-220			-
BUP 300	Sie	MOS-N-IGBT	=BUP 200:		18(GCE)	TO-3P			-
BUP 302	Sie	MOS-N-IGBT	=BUP 202:		18(GCE)	TO-3P			GT 15N101, GT 15Q101
BUP 303	Sie	MOS-N-IGBT	=BUP 203:		18(GCE)	TO-3P			-
BUP 304	Sie	MOS-N-IGBT	Iso-Gate bipolar Trans., 1000/20V, 35/50A, 310W		18(GCE)	TO-3P			-
BUP 307	Sie	MOS-N-IGBT	=BUP 304: 1200V		18(GCE)	TO-3P			-
BUR									
BUR 10	Sgs	Si-N	S P, 100/80V, 5A, 30W(Tc=100°), >50MHz, <80/140ns		22a	TO-66			-
BUR 11	Sgs	Si-N	S P, 300/200V, 20A, 175W, <500/1300ns		49m	TO-63			2N6324...6325
BUR 12	Sgs	Si-N	S P, 200/120V, 10A, 40W, <200/2150ns		49m	TO-59			2N5540
BUR 13	Sgs	Si-N	S P, 200/125V, 70/100A, 250W, 40MHz, 600/600ns		49m	TO-63			-
BUR 14	Sgs	Si-N	LF,S, 150/120V, 7W(Tc=25°), sat<1V(2,5V)	{BUR15	2a	TO-39			-
BUR 15	Sgs	Si-P	LF,S, 150/120V, 7W(Tc=25°), sat<1V(2,5A)	{BUR14	2a	TO-39			-
BUR 20	Sgs	Si-N	S P, 200/125V, 50/75A, 250W, 24MHz, 450/770ns		23a	TO-3			BUT 90, BUT 100, BUV 60
BUR 21	Sgs	Si-N	S P, 300/200V, 40/50A, 250W, 20MHz, 250/1200ns		23a	TO-3			BUS 51...52, BUV 22, BUX 22, BUV 61
BUR 22	Sgs	Si-N	S P, 350/250V, 40/50A, 250W, 20MHz, 250/1430ns		23a	TO-3			BUS 52, BUT 92, BUV 62
BUR 23	Sgs	Si-N	S P, 400/325V, 30/40A, 250W, 20MHz, <750/3800ns		23a	TO-3			BUV 23, BUX 23, 2N6323
BUR 24	Sgs	Si-N	=BUR 23: 450/400V		23a	TO-3			2SC2761, 2SC2930
BUR 30	Sgs	Si-P	S P, -/125V, 250W		23a	TO-3			-
BUR 31	Sgs	Si-P	S P, -/200V, 250W		23a	TO-3			-
BUR 32	Sgs	Si-P	S P, -/250V, 250W		23a	TO-3			-
BUR 33	Sgs	Si-P	S P, -/325V, 250W		23a	TO-3			-
BUR 34	Sgs	Si-P	S P, -/400V, 250W		23a	TO-3			-
BUR 50(S)	Sgs	Si-N	S P, 200/125V, 70/100A, 350W, 16MHz, 500/920ns		23a	TO-3			BUS 50
BUR 51	Sgs	Si-N	S P, 300/200V, 60/80A, 350W, 16MHz, 350/1140ns		23a	TO-3			-
BUR 52	Sgs	Si-N	S P, 350/250V, 60/80A, 350W, 16MHz, 300/1400ns		23a	TO-3			-
BUR 53	Sgs	Si-N	S P, -/325V, 350W		23a	TO-3			-
BUR 54	Sgs	Si-N	S P, -/400V, 350W		23a	TO-3			-
BUR 55	Sgs	Si-N	S P, -/600V, 250W		23a	TO-3			-
BUR 56	Sgs	Si-N	S P, -/700V, 250W		23a	TO-3			-
BUR 60	Sgs	Si-P	S P, -/125V, 350W		23a	TO-3			-
BUR 61	Sgs	Si-P	S P, -/200V, 350W		23a	TO-3			-
BUR 62	Sgs	Si-P	S P, -/250V, 350W		23a	TO-3			-
BUS									
BUS 11	Phi	Si-N	S P, 850/400V, 5/10A, 100W, <1/4,8µs		23a	TO-3	BUW 11 A	18j	BUX 47, BUX 83, 2SC3048, 2SD802, ++
BUS 11 A		Si-N	=BUS 11: 1000/450V		23a	TO-3	BUW 11 A	18j	BUX 83, MJ 8502, 2SC3060, 2SC3214, ++
BUS 12	Phi	Si-N	S P, 850/400V, 8/20A, 125W, <1/4,8µs		23a	TO-3	BUW 13 A	18j	BUW 36, BUX 81, MJ 8504, 2SC3061, ++
BUS 12 A		Si-N	=BUS 12: 1000/450V		23a	TO-3	BUW 13 A	18j	BUX 81, MJ 8504, 2SC3061, 2SC3215,++
BUS 13	Phi	Si-N	S P, 850/400V, 15/30A, 175W, <1/4,8µs		23a	TO-3	BUW 13 A	18j	BUW 13(A), BUW 46, BUX 48, 2SC3593,++
BUS 13 A		Si-N	=BUS 13: 1000/450V		23a	TO-3			BUW 13A, BUW 133A, 2SC3216
BUS 14	Phi	Si-N	S P, 850/400V, 30/50A, 250W, <1/4,8µs		23a	TO-3			BUS 24C, BUS 98(A), BUX 348(A)
BUS 14 A		Si-N	=BUS 14: 1000/450V		23a	TO-3			BUS 98A, BUX 348A
BUS 20	Phi	Si							
BUS 21	Phi	Si-N	S P, 550/300V, 5/10A, 100W, <1/5,2µs		23a	TO-3			BUS11(A), BUW11(A), BUX82...83, 2SC3048++
BUS 21 A		Si-N	=BUS 21: 650/350V		23a	TO-3			BUS11(A), BUW11(A), BUX82...83, 2SC3048++
BUS 21 B		Si-N	=BUS 21: 750/400V		23a	TO-3			BUS11(A), BUW11(A), BUX82...83, 2SC3048++
BUS 21 C		Si-N	=BUS 21: 850/450V		23a	TO-3			BUS11(A), BUW11(A), BUX 83, 2SC3048,++

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
BUS 22	Phi	Si-N	S P, 550/300V, 8/20A, 125W, 500/3300ns		23a TO-3			BUS 12(A), BUW 36, BUX 47(A), 2SD811, ++
BUS 22 A		Si-N	=BUS 22: 650/350V		23a TO-3			BUS 12(A), BUW 36, BUX 47(A), 2SD811, ++
BUS 22 B		Si-N	=BUS 22: 750/400V		23a TO-3			BUS 12(A), BUW 36, BUX 47(A), 2SD811, ++
BUS 22 C		Si-N	=BUS 22: 850/450V		23a TO-3			BUS 12(A), BUW 36, BUX 47(A), 2SD811, ++
BUS 23	Phi	Si-N	S P, 550/300V, 15/30A, 175W, 700/2270ns		23a TO-3			BUS13(A), BUS97(A), BUW13(A), BUW45...46+
BUS 23 A		Si-N	=BUS 23: 650/350V		23a TO-3			BUS13(A), BUS97(A), BUW13(A), BUW45...46+
BUS 23 B		Si-N	=BUS 23: 750/400V		23a TO-3			BUS13(A), BUS97(A), BUW13(A), BUW45...46+
BUS 23 C		Si-N	=BUS 23: 850/450V		23a TO-3			BUS 13(A), BUS 97(A), BUW 13(A), BUW 46+
BUS 24 A	Phi	Si-N						
BUS 24 B	Phi	Si-N	S P, 750/400V, 30/50A, 250W, <1/5,2µs		23a TO-3			BUS 14(A), BUS 98(A), BUX 348(A)
BUS 24 C		Si-N	=BUS 24B: 850/450V		23a TO-3			BUS 14(A), BUS 98(A), BUX 348(A)
BUS 25(A,B)	Phi	Si						
BUS 26(A)	Phi	Si						
BUS 27(A,B)	Phi	Si						
BUS 36	Mot	Si-N	S P, 250/120V, 12/40A, 107W, >30MHz, 220/620ns		17j TO-220			BUV 27(A), BUV 28(A)
BUS 37	Mot	Si-N	=BUS 36: 300/150V		17j TO-220			BUV 27A, BUV 28(A)
BUS 45 P	Mot	Si-N	S P, 850/450V, 3/5A, 75W, 130/575ns		17j TO-220			BUT 11(A), BUV 46(A), 2SC3490...3491, ++
BUS 46 P	Mot	Si-N	S P, 850/450V, 5/8A, 80W, 130/1675ns		17j TO-220			BUT 11(A), BUT 18(A), BUV 46(A), 2SC3047
BUS 47	Mot	Si-N	S P, 850/450V, 9/12A, 150W, 125/1600ns		23a TO-3			BUS 12(A), BUW 12(A), BUW 36, BUX 81,++
BUS 47 A		Si-N	=BUS 47: 1000/450V		23a TO-3			BUS 12A, BUW 12A, BUX 81, MJ 8504,++
BUS 47 AP		Si-N	=BUS 47: 1000/450V, 107W		18j TO-3P			BUV 47A, BUW 12A
BUS 47 P		Si-N	=BUS 47: 107W		18j TO-3P			BUV 47(A), BUW 12(A), 2SC36377
BUS 48	Mot	Si-N	S P, 850/450V, 15/20A, 175W, 160/2100ns		23a TO-3	BUW 13 A	18j	BUS 13(A), BUS 97, BUW 46, BUX 48,++
BUS 48 A		Si-N	=BUS 48: 1000/450V		23a TO-3	BUW 13 A	18j	BUS 13A, BUX 48A, 2SC3216
BUS 48 AP		Si-N	=BUS 48: 1000/450V, 125W		18j TO-3P	BUW 13 A	18j	BUV 48A...C, BUW 13A, BUW 133A, 2SC3552++
BUS 48 P		Si-N	=BUS 48: 125W		18j TO-3P	BUW 13 A	18j	BUV48(A...C), BUW13(A), BUW133(A),2SC3552
BUS 50	Mot	Si-N	S P, 200/125V, 70/140A, 350W, 1,2/1,8µs		23a TO-3			BUR 50
BUS 51	Mot	Si-N	S P, 300/200V, 50/100A, 350W, 1/2,3µs		23a TO-3			BUR 51
BUS 52	Mot	Si-N	=BUS 51: 350/250V, 40/80A		23a TO-3			BUR 52
BUS 97	Mot	Si-N	S P, 850/400V, 18/30A, 175W, 500/1500ns		23a TO-3			BUS13(A), BUW13(A), BUX48(A...C), 2SC3593
BUS 97 A		Si-N	=BUS 97: 1000/450V		23a TO-3			BUS 13A, BUW 13A, BUX 48A...C, 2SC3593,++
BUS 98	Mot	Si-N	S P, 850/450V, 30/60A, 250W, 500/1850ns		23a TO-3			BUS 14(A), BUS 24C, BUX 348(A)
BUS 98 A		Si-N	=BUS 98: 1000/450V		23a TO-3			BUS 14A, BUX 348A
BUS 131(H)	Phi	Si-N	S P, 850/450V, 5/10A, 125W, 350/1270ns		23a TO-3			BUS 11(A), BUX 83, 2SC3156, 2SD802, ++
BUS 131 A		Si-N	=BUS 131: 1000/500V		23a TO-3			BUS 11A, BUX 83, 2SC3060, 2SC3214, ++
BUS 132(H)	Phi	Si-N	S P, 850/450V, 8/16A, 150W, 350/1600ns		23a TO-3			BUS 12(A), BUW 36, BUX 81, 2SC3061, ++
BUS 132 A		Si-N	=BUS 132: 1000/500V		23a TO-3			BUS 12A, BUX 81, MJ 8504, 2SC3061, ++
BUS 133(H)	Phi	Si-N	S P, 850/450V, 15/20A, 175W, 400/1450ns		23a TO-3			BUS 13(A), BUS 97(A), BUW 46, BUX 48, ++
BUS 133 A		Si-N	=BUS 133: 1000/500V		23a TO-3			BUS 13A, BUS 97A, BUW 13A, BUX 48A...C,++
BUT								
BUT 11	Phi,Tho	Si-N	S P, 850/400, 5/10A, 100W, <1/4,8µs		17j TO-220	BUT 11 A	17j	BUT 18(A), BUS 46P, BUV 46(A), 2SC3047++
BUT 11 A		Si-N	=BUT 11: 1000/450V		17j TO-220	BUT 11 A	17j	BUT 18A, BUV 46A, MJE 8502, 2SC3050
BUT 11 F,AF	Phi	Si-N	=BUT 11(A): Iso, 20W		17c SOT-186	BUT 11 AF	17c	BUT 18(A)F, BUV 46FI,AFI
BUT 11 AX	Phi	Si-N	=BUT 11A: Iso, 20W		17c TO-220 Iso	BUT 11 AF	17c	›BUT 11AF
BUT 11 FI,AFI	Tho	Si-N	=BUT 11(A): Iso, 35W		17c TO-220Iso	BUT 11 AF	17c	BUT 18(A)F, BUV 46FI,AFI
BUT 12	Phi	Si-N	S P, 850/400, 6/8A, 125W, <1/4,8µs		17j TO-220	BUT 12 A	17j	BUT 76(A), BUV 56(A), BUV 66(A)
BUT 12 A		Si-N	=BUT 12: 5/8A, 125W		17j TO-220	BUT 12 A	17j	BUT 76A, BUV 56A, BUV 66A
BUT 12 AF	Phi	Si-N	=BUT 12(A): !so, 23W		17c SOT-186	BUT 12 AF	17c	BUT 22CF
BUT 12 FI,AFI	Tho	Si-N	=BUT 12(A): Iso		17c TO-220Iso	BUT 12 AF	17c	-
BUT 13	Mot,Tho	Si-N-Darl+Di	S P, 600/400V, 28/35A, 175W, <600/2100ns		23a TO-3			MJ 10023
BUT 13 P	Tho	Si-N-Darl+Di	=BUT 13: 150W		18j TO-3P			-
BUT 13 PFI	Tho	Si-N-Darl+Di	=BUT 13P: Iso, 60W		18c TO-3P Iso			-
BUT 14	Mot	Si-N-Darl+Di	S P, 850/500V, 25/35A, 175W, <1,9/4µs		23a TO-3			BUT 35...36
BUT 15	Mot	Si-N-Darl+Di	S P, 1000/700V, 20/25A, 175W, <1,2/3,8µs		23a TO-3			MJ 10024...10025
BUT 16	Mot	Si-N-Darl+Di	S P, 1400/1000V, 12/20A, 150W, <-/4,8µs		23a TO-3			-
BUT 18	Phi	Si-N	S P, 850/400V, 6/12A, 110W, <1/4,8µs		17j TO-220	BUT 56 A	17j	BUT 12(A), BUT 56(A)
BUT 18 A		Si-N	=BUT 18: 1000/450V		17j TO-220	BUT 56 A	17j	BUT 12A, BUT 56A
BUT 18(A)F		Si-N	=BUT 18(A): Iso, 33W		17c SOT-186	BUT 18 AF	17c	BUT 12(A)F
BUT 21 B	Phi	Si-N	S P, 750/400V, 5/10A, 100W, 500/3300ns		17j TO-220	BUT 56 A	17j	BUT 12(A), BUT 18(A), BUT 56(A)
BUT 21 BF		Si-N	=BUT 21B: Iso, 20W		17c SOT-186	BUT 18 AF	17c	BUT 11(A)F, BUT 12(A)F, BUT 18(A)F
BUT 21 C		Si-N	=BUT 21B: 850/450V		17j TO-220	BUT 56 A	17j	BUT 12(A), BUT 18(A), BUT 56(A)
BUT 21 CF		Si-N	=BUT 21C: Iso, 20W		17c SOT-186	BUT 18 AF	17c	BUT 11(A)F, BUT 12(A)F, BUT 18(A)F
BUT 22 B	Phi	Si-N	S P, 750/400V, 8/20A, 125W, 700/2270ns		17j TO-220	BUT 12 A	17j	BUT 12(A), BUT 76(A), BUV 56(A)
BUT 22 BF		Si-N	=BUT 22B: Iso, 23W		17c SOT-186	BUT 12 AF	17j	BUT 12(A)F
BUT 22 C		Si-N	=BUT 22B: 850/450V		17j TO-220	BUT 12 A	17j	BUT 12(A), BUT 76(A), BUV 56(A)
BUT 22 CF		Si-N	=BUT 22C: Iso, 23W		17c SOT-186	BUT 12 AF	17j	BUT 12(A)F
BUT 30(F,V)	Tho	Si-N	S P, 200/125V, 100A, 250W BUT 30(F): SOT-227B, BUT 30V: SOT-227A		=67 SOT-227			-
BUT 32(V)	Tho	Si-N	S P, 400/300V, 80A, 250W BUT 32(F): SOT-227B, BUT 32V: SOT-227A		=67 SOT-227			-
BUT 33	Mot	Si-N-Darl+Di	S P, 600/400V, 56/75A, 250W, <1,3/4,1µs		23a TO-3			MJ10015...10016
BUT 34	Mot	Si-N-Darl+Di	S P, 850/500V, 50/75A, 250W, <1,3/4µs		23a TO-3			-
BUT 35	Mot	Si-N-Darl+Di	S P, 1000/700V, 40/50A, 250W, <1,2/4,5µs		23a TO-3			-
BUT 36	Mot	Si-N-Darl+Di	S P, 1400/1000V, 24/40A, 250W, <-/8,5µs		23a TO-3			-
BUT 44 D	Aeg	Si-N+Di	S P, 700/400V, 4A, 63W, 160/-ns		17j TO-220			-
BUT 46	Aeg	Si-N	S P, SMPS, 850/400V, 5/10A, 75W, <1/4,8µs		17j TO-220	BUT 11 A	17j	BUT 11(A), BUT 18(A), BUV 46(A), ++
BUT 46 A		Si-N	=BUT 46: 1000/450V		17j TO-220	BUT 11 A	17j	BUT 11A, BUT 18A, BUV 46A, 2SC3050, ++
BUT 50 P	Mot	Si-N-Darl+Di	S P, 850/500V, 8/16A, 100W, -/850ns		18j TO-3P			2SC3030, 2SC3032
BUT 51 P	Mot	Si-N-Darl+Di	S P, 850/500V, 15/25A, 125W, -/1260ns		18j TO-3P			BUD 48
BUT 54	Aeg	Si-N	S P, SMPS, 800/430V, 8/10A, 100W, 10MHz, -/4µs		17j TO-220	BUT 56 A	17j	BUT 12(A), BUT 56(A), BUV 56
BUT 55	Tho	Si-N-Darl+Di	Kfz-Zündung/Ignition, 400/400V, 12A, 105W, hFE>100		17j TO-220			-
BUT 56	Aeg	Si-N	S P, SMPS, 800/400V, 8/10A, 100W, 10MHz, -/4µs		17j TO-220	BUT 56 A	17j	BUT 12(A), BUT 54, BUT 76(A), BUV 56(A)
BUT 56 A		Si-N	=BUT 56: 1000/450V		17j TO-220	BUT 56 A	17j	BUT 12A, BUT 76A, BUV 56A
BUT 56 A/668		Si-N	=BUT 56A		17j TO-220	BUT 56 A	17j	›BUT 56A
BUT 56 AF		Si-N	=BUT 56: Iso		17c	BUT 12 AF	17c	BUT 12AF
BUT 56 H,PH		Si-N	=BUT 56A		17j TO-220	(BUT 56 A)	17j	(›BUT 56A)
BUT 56 T		Si-N	=BUT 56A		17j TO-220	BUT 56 A	17j	›BUT 56A
BUT 57	Tho	Si-N-Darl+Di	S P, 400/400V, 15A, 110W, hFE>200		18j TO-3P			BU 932P, BUT 51P, 2SD1466
BUT 57 I		Si-N-Darl+Di	=BUT 57: Iso, 80W		18c TO-3P Iso			BU 932PFI
BUT 60	Tho	Si-N	S P, 200/125V, 15A, 125W, <-/1,7µs		17j TO-220			BUS 36...37, BUV 27(A)
BUT 62	Tho	Si-N	=BUT 60: 400/300V, <-/2,6µs		17j TO-220			BUV 28(A)
BUT 70	Tho	Si-N	S P, SMPS, 200/125V, 40A, 200W, sat<0,9V(70A)		18j TO-3P			-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BUT 70 I		Si-N	=BUT 70: Iso, 115W		18c	TO-3P Iso			-
BUT 71	Tho	Si-N	S P, SMPS, 300/200V, 40A, 175W, sat<0,9V(40A)		18j	TO-3P			-
BUT 71 I		Si-N	=BUT 71: Iso, 100W		18c	TO-3P Iso			-
BUT 72	Tho	Si-N	S P, SMPS, 400/300V, 40A, 200W, sat<0,6V(30A)		18j	TO-3P			-
BUT 72 I		Si-N	=BUT 72: Iso, 115W		18c	TO-3P Iso			-
BUT 76	Aeg	Si-N	S P, SMPS, 850/400V, 10/20A, 100W, <1/3,8µs		17j	TO-220	BUT 76 A	17j	BUV 56(A), BUV 66(A)
BUT 76 A		Si-N	=BUT 76: 1000/450V		17j	TO-220	BUT 76 A	17j	BUV 56A, BUV 66A
BUT 76 AF		Si-N	=BUT 76: Iso		17c		BUT 12 AF	17c	BUT 12AF
BUT 90	Tho	Si-N	S P, 200/125V, 50/120A, 250W, sat<0,9V(70A)		23a	TO-3			BUT 100
BUT 91	Tho	Si-N	S P, 300/200V, 50/70A, 250W, sat<1,2V(40A)		23a	TO-3			BUT 102
BUT 92	Tho	Si-N	S P, 400/300V, 50/75A, 250W, sat<1,2V(35A)		23a	TO-3			BUT 102
BUT 92 A		Si-N	=BUT 92: 400/300V		23a	TO-3			BUT 102
BUT 93	Aeg	Si-N	S P, SMPS, 600/350V, 4/6A, 55W, 9MHz, <-/3,3µs		17j	TO-220	BUT 11 A	17j	BUT 11(A), BUV 46(A), 2SC3086, 2SD841,++
BUT 93 D		Si-N+Di	integr. Damper-Diode		17j	TO-220			-
BUT 98	Aeg	Si-N	S P, 850/450V, 30A, 200W, sat<0,6V(20A)		18j	TO-3P			-
BUT 98 A		Si-N	=BUT 98: 1000/450V		18j	TO-3P			-
BUT 100	Tho	Si-N	P, 200/125V, 50/150A, 300W,<-/2,2µs, sat<0,9V(50A)		23a	TO-3			BUT 90...91
BUT 102	Tho	Si-N	P, 400/300V, 50/75A, 300W, <-/3,4µs, sat<0,9V(40A)		23a	TO-3			BUT 92A
BUT 131(H)	Phi	Si-N	S P, 850/450V, 5/10A, 80W, 350/1270ns BUT 131: hFE>5, BUT 131H: hFE>7, 400/1320ns		17j	TO-220	BUT 11 A	17j	BUT 11(A), BUT 18(A), BUV 46(A), ++
BUT 131 A		Si-N	=BUT 131(H): 1000/450V		17j	TO-220	BUT 11 A	17j	BUT 11A, BUT 18A, BUV 46A, 2SC3050, ++
BUT 211	Phi	Si-N	S P, 850/400, 5/10A, 100W, <-/2,8µs		17j	TO-220	BUT 11 A	17j	BUT 18(A), BUS 46P, BUV 46(A), 2SC3047++
BUT 230(F,V)	Tho	Si-N	S P, 200/125V, 200A, 300W, sat<1,5V(200A) BUT 230(F): SOT-227B, BUT 230V: SOT-227A		Iso	(EEBC)			-
BUT 232(F,V)	Tho	Si-N	S P, 400/300V, 140A, 300W BUT 232(F): SOT-227B, BUT 232V: SOT-227A		Iso	(EEBC)			-
BUV									
BUV 10	Mot	Si-N	LF,S P, 160/125V, 25/30A, 150W, >8MHz, <1,5/1,45µs		23a	TO-3			BUW 39, BUX 10, BUX 40, 2N6322
BUV 10 N		Si-N	=BUV 10: 175W, <1/1,95µs		23a	TO-3			2N6322
BUV 11	Mot	Si-N	LF,S P, 250/220V, 20/25A, 150W, >8MHz, <0,8/2,2µs		23a	TO-3			BUW 58, BUW 73, BUX 11...12, 2N6322
BUV 11 N		Si-N	=BUV 11: 220/160V, <1,5/2,25µs		23a	TO-3			BUW 58, BUW 73, BUX 11...12, 2N6322
BUV 12	Mot	Si-N	S P, 300/250V, 20/25A, 150W, >8MHz, <0,7/2µs		23a	TO-3			BUW 73, BUX 12, 2N6322
BUV 18	Tho	Si-N	S P, 120/60V, 50/90A, 250W, >8MHz, 1200/780ns		23a	TO-3			BUR 20, BUT 90, BUT 100, BUX 20
BUV 19	Tho	Si-N	S P, 160/80V, 50/70A, 250W, >8MHz, 900/770ns		23a	TO-3			BUR 20, BUT 90, BUT 100, BUX 20
BUV 20	Mot,Tho	Si-N	S P, 160/125V, 50/60A, 250W, >8MHz, 900/850ns		23a	TO-3			BUR 20, BUR 50, BUT 90, BUT 100, BUX 20
BUV 21	Mot,Tho	Si-N	S P, 250/200V, 40/50A, 250W, >8MHz, 850/1200ns		23a	TO-3			BUR 21...22, BUT 91, BUV 61, BUX 21...22
BUV 21 N		Si-N	=BUV 21: 220/160V		23a	TO-3			BUR 21...22, BUT 91, BUV 61, BUX 21...22
BUV 22	Mot,Tho	Si-N	S P, 300/250V, 40/50A, 250W, >8MHz, 750/1450ns		23a	TO-3			BUR 21...22, BUT 91, BUV 61...62, BUX 22
BUV 23	Mot,Tho	Si-N	S P, 400/325V, 30/40A, 250W, >8MHz, 550/1960ns		23a	TO-3			BUT 92A, BUT 102, BUV 23, BUX 23, 2N6323
BUV 24	Mot,Tho	Si-N	S P, 450/400V, 20/30A, 250W, >8MHz, 600/2100ns		23a	TO-3			BUV 24, BUX 24
BUV 25	Mot,Tho	Si-N	S P, 500/500V, 15/20A, 250W, >8MHz, 900/4400ns		23a	TO-3			BUV 25, BUW 44, BUX 25
BUV 26	Mot,Phi,Tho	Si-N	S P, 180/90V, 20/30A, 85W, 400/540ns		17j	TO-220			-
BUV 26 A		Si-N	=BUV 26: 200/100V		17j	TO-220			-
BUV 26 F,AF	Phi	Si-N	=BUV 26(A): Iso, 18W		17c	SOT-186			-
BUV 27	Mot,Phi,Tho	Si-N	S P, 240/120V, 15/25A, 85W, 400/620ns		17j	TO-220			BUS 36...37
BUV 27 A		Si-N	=BUV 27: 300/150V		17j	TO-220			BUS 37
BUV 27 F,AF	Phi	Si-N	=BUV 27(A): Iso, 18W		17c	SOT-186			-
BUV 28	Mot,Phi,Tho	Si-N	S P, 400/200V, 12/20A, 85W, <1/2,5µs		17j	TO-220			MJE 13008...13009, 2SC4164
BUV 28 A		Si-N	=BUV 28: 450/225V		17j	TO-220			MJE 13008...13009, 2SC4164
BUV 28 F,AF	Phi	Si-N	=BUV 28(A): Iso, 18W		17c	SOT-186			2SC4163
BUV 30	Aeg	Si-N-Darl+Di	S P, -/400V, 8A, 83W, hFE>250		17j	TO-220			-
BUV 36	Tho	Si-N	S P, 850/400V, 2A, 50W, <500/2,9µs		17j	TO-220	BUT 11 A	17j	BUT 11(A), BUS 45, BUV 46(A), BUX 85, ++
BUV 36 A		Si-N	=BUV 36: 1000/450V		17j	TO-220	BUT 11 A	17j	BUT 11A, BUV 46A, BUX 85, 2SC3491, ++
BUV 37	Tho	Si-N-Darl	S P, 450/400V, 15A, 125W, hFE>20		18j	TO-3P			BU 932P, 2SD1466
BUV 39	Tho	Si-N	S P, 160/90V, 25/45A, 120W, <-/1,25µs		23a	TO-3			BUV 10, BUX 10, BUX 40, 2N6322
BUV 40	Tho	Si-N	S P, 250/125V, 20/30A, 120W, <-/1,3µs		23a	TO-3			BUV 11, BUW 58, BUX 11, 2N6322
BUV 41	Tho	Si-N	S P, 300/200V, 15/20A, 120W, <-/1,5µs		23a	TO-3			BUV 12, BUW 73, BUX 12, 2N6322
BUV 42	Tho	Si-N	S P, 350/250V, 12/18A, 120W, <-/1,9µs		23a	TO-3			BUW 74, BUX 13, BUY 50, MJ 15024
BUV 42 A		Si-N	=BUV 42: 400/300V		23a	TO-3			BUW 74, BUX 13, BUY 50, MJ 15024
BUV 46	Phi,Tho,Tix	Si-N	S P, 850/400V, 6/8A, 85W, 12MHz, <1/3,8µs		17j	TO-220	BUT 11 A	17j	BUT 11(A), BUT 18(A), BUT 56(A), 2SC3047
BUV 46 A		Si-N	=BUV 46: 1000/450V		17j	TO-220	BUT 11 A	17j	BUT 11A, BUT 18A, BUT 56A, 2SC3050, ++
BUV 46 FI,AFI	Tho	Si-N	=BUV 46(A): Iso, 30W		17c	TO-220Iso	BUT 18 AF	17c	BUT 11(A)F, BUT 12(A)F, BUT 18(A)F
BUV 47(B)	Aeg,Phi,Tho	Si-N	S P, 850/400V, 9/15A, 120W, 7MHz, <1/3.8µs		18j	TO-3P	BUV 70	18j	BUV 48(A...C), BUW 12(A)...13(A), 2SC3552
BUV 47 A		Si-N	=BUV 47(B): 1000/450V		18j	TO-3P	BUV 70	18j	BUV 48A...C, BUW 12A...13A, 2SC3552
BUV 47 AF	Aeg	Si-N	=BUV 47A: Iso		18c				BUW 12AF, 2SC4429
BUV 47 F	Aeg	Si-N	=BUV 47: Iso		18c				BUW 12(A)F, BUP 22CF, 2SC4429
BUV 47 FI,AFI	Tho	Si-N	=BUV 47(A): Iso, 55W		18c	TO-3P Iso			BUW 12(A)F, BUP 22CF, 2SC4429
BUV 48	Aeg,Phi,Tho	Si-N	S P, 850/400V, 15/30A, 150W, 5MHz, <1/3,8µs		18j	TO-3P	BUW 13 A	18j	BUW 13(A), BUW 133(A), 2SC3552
BUV 48 A		Si-N	=BUV 48: 1000/450V		18j	TO-3P	BUW 13 A	18j	BUW 13A, BUW 133A, 2SC3552
BUV 48 AF	Aeg	Si-N	=BUV 48A: Iso		18c				BUW 13AF, BUX 98API
BUV 48 B		Si-N	=BUV 48: 1200/600V		18j	TO-3P			2SC3644
BUV 48 C		Si-N	=BUV 48: 1200/700V		18j	TO-3P			2SC3644
BUV 48 F	Aeg	Si-N	=BUV 48: Iso		18c				BUP 23CF, BUW 13(A)F, BUX 98(A)PI
BUV 48 FI,AFI	Tho	Si-N	=BUV 48(A): Iso, 65W		18c	TO-3P Iso			BUP 23CF, BUW 13(A)F, BUX 98(A)PI
BUV 48 T		Si-N	=BUV 48: sat<0,9V(10A)		18j	TO-3P			-
BUV 50	Tho	Si-N	S P, 250/125V, 25/50A, 150W, <-/1,6µs		23a	TO-3			BUV 11, BUW 58, BUX 11, 2N6322
BUV 51	Tho	Si-N	S P, 300/200V, 20/28A, 150W, <-/2µs		23a	TO-3			BUV 12, BUW 73, BUX 12, 2N6322
BUV 52	Tho	Si-N	S P, 350/250V, 20/30A, 150W, <-/2,2µs		23a	TO-3			BUV 23...24, BUX 23...24, 2N6323
BUV 52 A		Si-N	=BUV 52: 400/300V		23a	TO-3			BUV 23...24, BUX 23...24, 2N6323
BUV 54	Tho	Si-N-Darl	S P, -/400V, 18A, 150W, hFE>20		23a	TO-3			BUT 15, MJ 10024...10025
BUV 54 A		Si-N-Darl	=BUV 54: -/600V		23a	TO-3			MJ 10025
BUV 56	Tho	Si-N	S P, 850/400V, 9/14A, 70W, <1/3,4µs		17j	TO-220			BUT 76(A), BUV 66(A)
BUV 56 A		Si-N	=BUV 56: 1000/450V		17j	TO-220			BUT 76A, BUV 66A
BUV 60	Tho	Si-N	S P, 250/125V, 50/80A, 250W, <-/1,3µs		23a	TO-3			BUR 51...52, BUS 51, BUT 91
BUV 61	Tho	Si-N	S P, 300/200V, 50/75A, 250W, <-/1,5µs		23a	TO-3			BUR 51...52, BUS 51, BUT 91
BUV 62	Tho	Si-N	S P, 350/250V, 40/60A, 250W, <-/2,15µs		23a	TO-3			BUR 22, BUS 52, BUT 92
BUV 62 A		Si-N	=BUV 62: 400/300V		23a	TO-3			BUT 92A, BUT 102
BUV 63	Aeg	Si-N	S P, 600/350V, 1,5A, 10W, tf<700ns		13h	TO-202			BUV 93...95
BUV 66	Tho	Si-N	S P, 850/400V, 15/22A, 100W, <1/3,4µs		17j	TO-220			-
BUV 66 A		Si-N	=BUV 66: 1000/450V		17j	TO-220			-
BUV 70	Aeg	Si-N	S P, 1300/550V, 10/15A, 140W, 9MHz, <0,5/4,6µs		18j	TO-3P	BUV 70	18j	2SC4023
BUV 70 F		Si-N	=BUV 70: Iso		18c				2SC4199(A)

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BUX 44	Mot,Rca,Sgs	Si-N	S P, 450/400V, 8/10A, 120W, >8MHz, <1/3,7µs		23a	TO-3			BUW 25, BUW 34, BUX 15, BUX 18C, ++
BUX 45	Mot,Rca,Sgs	Si-N	S P, 500/500V, 5/7A, 120W, >8MHz, <1/6,2µs		23a	TO-3			BUS 11(A), BUX 47, BUX 82…83, BUX 97,++
BUX 46	Mot,Phi,Sgs	Si-N	=BUV 46:		23a	TO-3			BUS 11(A), BUX 83, MJ 8502, 2SC3156,++
BUX 46 A		Si-N	=BUV 46A:		23a	TO-3			BUS 11A, BUX 83, MJ 8502, 2SC3060, ++
BUX 47(B)	Mot,Phi,++	Si-N	=BUV 47(B): 125W		23a	TO-3			BUS 12(A), BUW 36, BUX 81, MJ 8504, ++
BUX 47 A		Si-N	=BUV 47A: 125W		23a	TO-3			BUS 12A, BUX 81, MJ 8504, 2SC3061, ++
BUX 48	Mot,Phi	Si-N	=BUV 48: 175W		23a	TO-3			BUS 13(A), BUS 97, BUW 46, 2SC3216
BUX 48 A		Si-N	=BUV 48A: 175W		23a	TO-3			BUS 13A, 2SC3216
BUX 48 B		Si-N	=BUV 48B: 175W		23a	TO-3			2SC3216
BUX 48 C		Si-N	=BUV 48C: 175W		23a	TO-3			2SC3216
BUX 49	Tho	Si-N	S, 150/90V, 3,5/7A, 10W(Tc=25°), >8MHz, <0,8/1,8µs		2a	TO-39			BU 125(S), BUX 50…53, BUY 49, 2SD625
BUX 50	Tho	Si-N	S,200/125V, 3,5/7A, 10W(Tc=25°), >8MHz, <0,8/2,3µs		2a	TO-39			BU 125(S), BUX 51…53, BUY 49, 2SD625
BUX 51	Tho	Si-N	S, 300/200V, 3,5/5A, 10W(Tc=25°), >8MHz, <0,8/3µs		2a	TO-39			BUX 52…53, BUY 61…62
BUX 51 N		Si-N	=BUX 51: 250/160V		2a	TO-39			BUX 52…53, BUY 61…62
BUX 52	Tho	Si-N	S, 350/250V, 3,5A, 10W(Tc=25°), >8MHz, <1/3,3µs		2a	TO-39			BUX 53, BUY 61…62
BUX 53	Tho	Si-N	S, 425/325V, 3A, 10W(Tc=25°), >8MHz, <1/3,5µs		2a	TO-39			BUY 61…62
BUX 54	Tho	Si-N	S, 450/400V, 2/2,5A, 10W(Tc=25°), >8MHz, <1/3,5µs		2a	TO-39			BUY 61…62, 2SC1862
BUX 55	Tho	Si-N	S, 500/500V, 1A, 10W(Tc=25°), >8MHz, <1/5,5µs		2a	TO-39			BUY 59…60
BUX 56	Sie	Si-N-Darl	8A, 40W, hFE>200		17j	TO-220			-
BUX 57	Sie	Si-N-Darl	8A, 40W, hFE>100		17j	TO-220			-
BUX 59	Tho	Si-N	S P, 120/90V, 8A, 70W, >8MHz		22a	TO-66			BUS 36…37, BUV 27(A), 2SC2867, 2SC2334+
BUX 60	Tho	Si-N	S P, 160/125V, 8A, 70W, >8MHz		22a	TO-66			BUS 36…37, BUV 27(A), 2SC2867, 2SC3834+
BUX 61	Tho	Si-N	S P, 250/200V, 8A, 70W, >8MHz		22a	TO-66			BU 409, BUS 36…37, BUV 27(A), 2SC2867++
BUX 62	Tho	Si-N	S P, 300/250V, 7A, 70W, >8MHz		22a	TO-66			BUS 36…37, BUV 27(A), 2SC2867, 2SC3170+
BUX 63	Tho	Si-N	S P, 400/325V, 5A, 70W, >8MHz		22a	TO-66			BUT 56(A), MJE 52T…53T, 2N6498, 2SC3056
BUX 64	Tho	Si-N	S P, 450/400V, 4A, 70W, >8MHz		22a	TO-66			BUT 93, BUT 56(A), MJE 53T, 2N6499, ++
BUX 65	Tho	Si-N	S P, 500/500V, 3A, 70W, >8MHz		22a	TO-66			BUT 93, BUT 56(A), TIP 75C, 2SC4105, ++
BUX 66	Rca	Si-P	S P, 200/150V, 2/5A, 35W, >20MHz,<600/3100ns	{BUX67	22a	TO-66			2N6211…6214, 2SA1009(A), 2SB630
BUX 66 A		Si-P	=BUX 66: 300/250V		22a	TO-66			2N6212…14, 2SA1009(A), 2SA1236
BUX 66 B		Si-P	=BUX 66: 350/300V		22a	TO-66			2N6212…14, 2SA1009(A), 2SA1236
BUX 66 C		Si-P	=BUX 66: 400/350V		22a	TO-66			2N6213…14, 2SA1009A, 2SA1236
BUX 67	Rca	Si-N	S P, 200/150V, 2/5A, 35W, >10MHz, <3/7µs	{BUX66	22a	TO-66			2N3583…85, 2SC2023, 2SC3055, 2SD610, ++
BUX 67 A		Si-N	=BUX 67: 300/250V		22a	TO-66			2N3584…85, 2SC2023, 2SC2333, 2SC3055,++
BUX 67 B		Si-N	=BUX 67: 350/300V		22a	TO-66			2N3584…85, 2SC2534, 2SC2333, 2SC3055,++
BUX 67 C		Si-N	=BUX 67: 400/350V		22a	TO-66			2N3585, 2SC2534, 2SC2333, 2SC3055, ++
BUX 69	Tho	Si-N	S P, 180/90V, 30/40A, 125W, 8MHz, <1,5/1,3µs		18j	TO-3P			BUW 60
BUX 70	Tho	Si-N	S P, 250/125V, 20/28A, 125W, 8MHz, <1,2/1,6µs		18j	TO-3P			BUW 50…52
BUX 71	Sie	Si-N	S P, 600/600V, 20/30A, 200W, 10MHz		38a	TO-68			-
BUX 72	Sie	Si-N	S P, 500/500V, 40/60A, 200W, 10MHz		38a	TO-68			-
BUX 73	Sie	Si-N	S P, 400/400V, 60/75A, 200W, 10MHz		38a	TO-68			-
BUX 74	Sie	Si-N	S P, 300/300V, 100/150A, 200W, 10MHz		38a	TO-68			-
BUX 75	Sie	Si-N	S P, 220/200V, 150/200A, 200W, 10MHz		38a	TO-68			-
BUX 76	Sie	Si-N	S P, 120/100V, 200/250A, 200W, 10MHz		38a	TO-68			-
BUX 77	Sgs	Si-N	S P, 100/80V, 5A, 40W, >2,5MHz, <300/700ns	{BUX78	22a	TO-66			BU 409, 2N6233…35, 2SC2767, 2SC3035,++
BUX 78	Sgs	Si-P	S P, 100/80V, 5A, 40W, >2,5MHz, <300/700ns	{BUX77	22a	TO-66			BUW 22P, MJE 5850…52, 2SA1250, 2SA1500
BUX 80	Phi,Sie,++	Si-N	P,800/400V, 10/15A, 100W(Tc=40°), 6MHz,<300/3800ns		23a	TO-3			BUS 12(A), BUW 26, BUW 35…36, MJ 8504++
BUX 81	Phi,Sie,++	Si-N	=BUX 80: 1000/450V		23a	TO-3			BUS 12A, MJ 8504, 2SC3061, 2SC3215, ++
BUX 82	Phi,Sie,++	Si-N	P, 800/400V, 6/8A, 60W(Tc=50°), 6MHz, <500/3800ns		23a	TO-3			BUS 11(A), BUX 47(A), MJ 8502, 2SC3060++
BUX 83	Phi,Sie	Si-N	=BUX 82: 1000/450V		23a	TO-3			BUS 11A, BUX 47A, MJ 8502, 2SC3060, ++
BUX 84(A)	Phi,Sie,++	Si-N	P, 800/400V, 2/3A, 40W(Tc=50°), 20MHz, <500/3900ns BUX 84: sat<3V(1A), BUX 84A: sat<1V(1A)		17j	TO-220	BUX 85	17j	BUV 36(A), MJE 8500, 2SC3178, 2SC3531,++
BUX 84 F	Phi	Si-N	=BUX 84: Iso, 18W		17c	SOT-186	BUT 11 AF	17c	BUT 11(A), 2SC3352, 2SC3794, 2SC4304,++
BUX 85	Phi,Sie,++	Si-N	=BUX 84: 1000/450V		17j	TO-220	BUX 85	17j	BUV 36A, MJE 8501, 2SC3178, 2SC3531, ++
BUX 85 F	Phi	Si-N	=BUX 85: Iso, 18W		17c	SOT-186	BUT 11 AF	17c	BUT 11AF, 2SC3752, 2SC3978A, 2SC4234,++
BUX 86	Aeg,Phi,Sie	Si-N	P,800/400V, 0,5/1A, 20W(Tc=60°), 20MHz,<500/3900ns		14h	TO-126			BUV 94…95
BUX 87	Aeg,Phi,Sie	Si-N	=BUX 86: 1000/450V		14h	TO-126			BUV 95
BUX 86P…87P	Phi	Si-N	=BUX 86…87: 42W		≈14j	SOT-82			-
BUX 88	Phi	Si-N	S P, SMPS, 1500/800V, 12/20A, 160W, 7MHz, 0,2/4µs		23a	TO-3			BU 808[Phi], BU 2525A, BUH 1015T
BUX 90	Phi	Si-N-Darl+Di	S P, 650/400V, 12/30A, 125W		23a	TO-3			BUD 48D, BUT 51P, (BUW 81A)[2]
BUX 91	Sie	Si-N	=BUX 71: 300W		49m	TO-114			-
BUX 92	Sie	Si-N	=BUX 72: 300W		49m	TO-114			-
BUX 93	Sie	Si-N	=BUX 73: 300W		49m	TO-114			-
BUX 94	Sie	Si-N	=BUX 74: 300W		49m	TO-114			-
BUX 95	Sie	Si-N	=BUX 75: 300W		49m	TO-114			-
BUX 96	Sie	Si-N	=BUX 76: 300W		49m	TO-114			-
BUX 97	Rca,Sgs,Tix	Si-N	P, 750/350V, 6/8A, 60W(Tc=75°), 20MHz, 600/2500ns		23a	TO-3			BUS 11(A), BUX 82…83, MJ8502, 2SC3048++
BUX 97 A		Si-N	=BUX 97: 800/400V		23a	TO-3			BUS 11(A), BUX 82…83, MJ8502, 2SC3048++
BUX 97 B		Si-N	=BUX 97: 800/450V		23a	TO-3			BUS 11(A), BUX 82…83, MJ8502, 2SC3048++
BUX 98	Phi,Sgs,Tix	Si-N	S P, 850/400V, 30/60A, 250W, 5MHz, <1/3,8µs		23a	TO-3			BUS 14(A), BUS 24C, BUS 98(A), BUX 348A
BUX 98 A		Si-N	=BUX 98: 1000/450V		23a	TO-3			BUS 14A, BUS 98A, BUX 348A
BUX 98 AP		Si-N	=BUX 98A: 24A, 200W		18j	TO-3P			BUT 98A
BUX 98 API		Si-N	=BUX 98A: Iso, 24A, 100W		18c	TO-3P Iso			-
BUX 98 B		Si-N	=BUX 98: 1000/600V		23a	TO-3			BUS 14A, BUS 98A, BUX 348A
BUX 98 C		Si-N	=BUX 98: 1200/700V		23a	TO-3			-
BUX 98 P		Si-N	=BUX 98: 200W		18j	TO-3P			BUT 98(A)
BUX 98 PI		Si-N	=BUX 98: Iso, 100W		18c	TO-3P Iso			-
BUX 99	Phi	Si-N	S P, 730/300V, 1,5/3A, 28W, 4MHz, <-/2,8µs		14h	TO-126			(BUV 94)[4]
BUX 100	Phi	Si-N	S P, 600/300V, 2/3A, 60W, <650/6500ns		≈14j	SOT-82			(BUT 93, BUX 84)[4]
BUX 127	Aeg	Si-N-Darl	S P, -/400V, 15A, 125W, hFE>200		18j	TO-3P			BU 931P…932P, BUV 37, BUT 51P
BUX 348	Phi,Tho	Si-N	P, 850/400V, 45/60A, 300W, <-/4,9µs, sat<0,9V(30A)		23a	TO-3			-
BUX 348 A		Si-N	=BUX 348: 1000/450V, 35A		23a	TO-3			BUS 14A, BUS 98A
BUY									
BUY 10	Itt	Si-N	S P, 40/20V, 0,8/2,4A, 10W(Tc=100°), 90MHz, hFE>15		23a	TO-3			(BDY 90…92)
BUY 11	Itt	Si-N	=BUY 10: hFE=40…100, 140MHz		23a	TO-3			(BDY 90…92)
BUY 12	Sie	Si-N	S P, 210/80V, 10A, 70W(Tc=45°), 11MHz, 500/680ns		23a/3Pin	TO-41			BUW 24, BUX 17, BUX 42…43, BUY 18, ++
BUY 12 S	Tho	Si-N	=BUY 12: 210/90V, 85W(Tc=45°)		23a	TO-3			BUW 24, BUX 17, BUX 42…43, BUY 18, ++
BUY 12 T	Tsm	Si-N	=BUY 12: 200/-V, 50W(Tc=80°)		23a	TO-3			BUW 24, BUX 17, BUX 42…43, BUY 18, ++
BUY 13	Sie	Si-N	=BUY 12: 120/70V		23a/3Pin	TO-41			BUW 70, BUX 17, BUX 42…43, BUY 18, ++
BUY 13 S	Tho	Si-N	=BUY 12: 120/70V, 85W(Tc=45°)		23a	TO-3			BUW 70, BUX 17, BUX 42…43, BUY 18, ++
BUY 14	Sie	Si-N	S P, 60/60V, 8A, 35W(Tc=35°), 11MHz, 500/680ns		22a	TO-66			BU 409, BUW 64A…C, 2SC2334, 2SC3255,++
BUY 16	Sgs	Si-N	S P, 150/80V, 10A, 15W(Tc=100°), 100MHz, hFE>40		49m	TO-59			(2N5542)[6]
BUY 17	Sgs	Si-N	=BUY 16: 120/60V, hFE=100…300		49m	TO-59			(2N5288…5289)[6]

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BUY 18	Tho	Si-N	S P, 300/150V, 10A, 25W(Tc=100°), 50MHz, 400/900ns		23a	TO-3			BUW 24, BUW 34, BUW 72, BUX 17A…C, ++
BUY 18 S		Si-N	S P, 400/200V, 7/10A, 50W(Tc=75°), 30MHz, <1/1µs		23a	TO-3			BUW 24, BUW 34, BUW 72, BUX 17B…C, ++
BUY 19	Sgs	Si-N	S P, 80/40V, 10A, 20W(Tc=100°), 100MHz, <350/-ns		49m	TO-59			(2N5288…5289)[6]
BUY 20	Tix	Si-N	S P, 200/120V, 10/15A, 85W, 25MHz, <1/1,1µs		23a	TO-3			BUW 24, BUW 34, BUX 17(A…C), BUX 43, ++
BUY 21	Tix	Si-N	=BUY 20: 300/180V		23a	TO-3			BUW 24, BUW 34, BUX 17A…C, BUX 43, ++
BUY 21 A		Si-N	=BUY 20: 400/230V		23a	TO-3			BUW 24, BUW 34, BUX 17B…C, BUX 43, ++
BUY 22	Tix	Si-N	=BUY 20: 450/230V		23a	TO-3			BUW 24, BUW 34, BUX 17C, BUX 14, ++
BUY 23	Tix	Si-N	S P, 600/250V, 10/15A, 85W, 25MHz, 1/1,1µs		23a	TO-3			BUS 12(A), BUW 26, BUW 35…36, BUX 80,++
BUY 23 A		Si-N	=BUY 23: 700/300V		23a	TO-3			BUS 12(A), BUW 26, BUW 35…36, BUX 80,++
BUY 23 B		Si-N	=BUY 23: 700/400V		23a	TO-3			BUS 12(A), BUW 26, BUW 35…36, BUX 80,++
BUY 24	Sgs	Si-N	S P, 120/60V, 5A, 15W(Tc=75°), 100MHz, 150/350		23a	TO-3			BDY 90, BUW 86…87, BUX 16(A…C), ++
BUY 26	Sie	Si-N	S P, 200/150V, 10A, 100W(Tc=45°), 20/63µs		53b	≈TO-49			-
BUY 27	Sie	Si-N	=BUY 26: 350/250V		53b	≈TO-49			-
BUY 28	Sie	Si-N	=BUY 26: 420/300V		53b	≈TO-49			-
BUY 29	Mot	Si-N	S P, -/200V, 8A, 125W, >50MHz, <600/400ns		23a	TO-3			BUX 18(A…C), BUX 43…44, BUY 18S, ++
BUY 30	Mot	Si-N	=BUY 29: -/250V		23a	TO-3			BUX 18(A…C), BUX 43…44, BUY 18S, ++
BUY 32/40	Aeg	Si-N	S P, -/40V, 6A, 60W, 0,8MHz		23a	TO-3			BD 245(A…C), BUW 86…87, 2N3055, ++
BUY 32/70		Si-N	=BUY 32/40: -/70V		23a	TO-3			BD 245A…C, BUW 86…87, 2N3055, ++
BUY 32/100		Si-N	=BUY 32/40: -/100V		23a	TO-3			BD 245C, BUW 86…87, 2N3055, ++
BUY 33/40	Aeg	Si-N	S P, -/40V, 10A, 90W, 0,8MHz		23a	TO-3			BD 245(A…C), BUW 86…87, 2N3055, ++
BUY 33/70		Si-N	=BUY 33/40: -/70V		23a	TO-3			BD 245A…C, BUW 86…87, 2N3055, ++
BUY 33/100		Si-N	=BUY 33/40: -/100V		23a	TO-3			BD 245C, BUW 86…87, 2N3055, ++
BUY 35	Sie	Si-N	S P, 350/300V, 6/8A, 50W(Tc=50°), 20MHz		23a	TO-3			BUW 71, BUX 16B…C, BUX 18A…C, 2SC3041+
BUY 38	Sgs	Si-N	LF,S P, 90/55V, 4A, 25W, >0,8MHz		22a	TO-66			BD 243B…C, BD 543B…D, 2N3054, 2SD613++
BUY 39	Tis	Si-N	S P, 100/80V, 5A, 30W(Tc=100°), >40MHz, 300/1500ns		50g	TO-111			2N3996…3997
BUY 40	Tix	Si-N	=BUY 39:		≈50m	TO-111a			2N3998…3999
BUY 41	Tix	Si-N	S P, 125/80V, 3A, 15W(Tc=100°), >40MHz, 200/350ns		2a	TO-39			BU 125(S), BUX 49…53, BUY 41, BUY 49
BUY 43	Sie	Si-N	LF,S P, 50/40V, 4A, 31W(Tc=45°), 1MHz		22a	SOT-9			BD 243(A…C), BD 543(A…D), BDW 25, ++
BUY 44	Sie	Si-N	S P, 330/150V, 7/10A, 30W(Tc=125°), 15MHz		23a	TO-3			BUX 18A…C, BUX 43…44, BUY 18S, ++
BUY 46	Mot,Sgs,Sie	Si-N	LF,S P, 90/60V, 4A, 31W(Tc=45°), >0,8MHz		22a	TO-66			BD 243B…C, BD 543B…D, BDW 25, ++
BUY 47	Sgs	Si-N	S P, 150/120V, 7/10A, 10W(Tc=50°), 90MHz, <1/2µs		2a	TO-39			BUY 68, BUY 81
BUY 48	Sgs	Si-N	=BUY 47: 200/170V		2a	TO-39			-
BUY 49	Sgs	Si-N	=BUY 47: 250/200V		2a	TO-39			-
BUY 49 P	Mot,Sgs	Si-N	=BUY 49: 3/5A, 15W, <0,8/2,5µs		14h	TO-126			-
BUY 49 S	Mot,Sgs	Si-N	=BUY 49: 3/5A, 0,3/1µs		2a	TO-39			BU 125S, BUX 51…52, 2SD625
BUY 50	Aeg	Si-N	S P, 400/250V, 15/17A, 95W(Tc=45°), 13MHz,<0,5/5µs		23a	TO-3			BUV 25, BUW 44, BUX 13, MJ 15024, ++
BUY 51	Tix	Si-N	S P, 60/60V, 30A, 150W, >10MHz, <1,5/2µs		49m	TO-61			(2N2823…2825)[6]
BUY 51 A		Si-N	=BUY 51:		23a	TO-3			BUW 38…39, BUX 39, 2N6322
BUY 52	Tix	Si-N	=BUY 51: <2/2µs		49m	TO-61			(2N2823…2825)[6]
BUY 52 A		Si-N	=BUY 51: <2/2µs		23a	TO-3			BUW 38…39, BUX 39, 2N6322
BUY 53	Tix	Si-N	=BUY 51: 100/100V		49m	TO-61			(2N2824…2825)[6]
BUY 53 A		Si-N	=BUY 51: 100/100V		23a	TO-3			BUW 38…39, BUX 39, 2N6322
BUY 54	Tix	Si-N	=BUY 51: 100/100V, <2/2µs		49m	TO-61			(2N2824…2825)[6]
BUY 54 A		Si-N	=BUY 51: 100/100V, <2/2µs		23a	TO-3			BUW 38…39, BUX 39, 2N6322
BUY 55	Sie	Si-N	S P, 150/125V, 10/15A, 60W(Tc=75°), 20MHz, <1/2µs		23a	TO-3			BUW 70, BUX 17(A…C), BUX 42, BUY 18, ++
BUY 56	Sie	Si-N	=BUY 55: 250/160V		23a	TO-3			BUW 74, BUX 17A…C, BUX 42, BUY 18, ++
BUY 57	Sie	Si-N	S P, 150/125V, 15/25A, 117W, 20MHz, <1/2,2µs		23a	TO-3			BUW 58, BUW 73, BUX 13, BUX 41, ++
BUY 58	Sie	Si-N	=BUW 57: 250/160V		23a	TO-3			BUW 58, BUW 73, BUX 13, BUX 41, ++
BUY 59	Tix	Si-N	LF,S, 500/325V, 1A, 10W(Tc=25°), >2,5MHz		2a	TO-39			BUX 55, 2N5095, 2N5097…5099
BUY 60	Tix	Si-N	=BUY 59: 600/400V		2a	TO-39			2N5097…5099
BUY 61	Tix	Si-N	LF,S, 500/325V, 3A, 10W(Tc=25°), >2,5MHz		2a	TO-39			(BUT 93, 2SC2826, 2SC3038)[6]
BUY 62	Tix	Si-N	=BUY 61: 600/400V		2a	TO-39			(BUT 93)[6]
BUY 63	Tix	Si-N	LF,S P, 500/325V, 3A, 20W, >2,5MHz		22a	TO-66			BUT 93, MJ 4380…4381, 2SC1467, 2SC2826
BUY 64	Tix	Si-N	=BUY 63: 600/400V		22a	TO-66			BUT 93, MJ 4380…4381
BUY 65	Tix	Si-N	LF,S P, 600/400V, 10A, 30W(Tc=100°), >2,5MHz		22a	TO-66			BUV 56(A), BUV 66(A), MJE 13008…13009
BUY 66	Tix	Si-N	LF,S P, 400/325V, 12,5/25A, 100W, >10MHz		23a	TO-3			BUW 44, BUW 74…77, BUX 13, BUY 50, ++
BUY 67	Tix	Si-N	LF,S P, 400/350V, 5A, 75W(Tc=100°), >10MHz		23a	TO-3			BUW 71, BUX 15, BUX 16C, BUX 44…45, ++
BUY 68	Sgs	Si-N	LF,S, 100/60V, 7A, 10W(Tc=50°), >50MHz		2a	TO-39			BU 125, BUY 47…49, BUY 81, 2N5338…39
BUY 69 A	Mot,Tix,++	Si-N	S P, TV-HA, 1000/400V, 10/15A, 100W, 10MHz,0,2/2µs		23a	TO-3	S 2530 A	23a	BU 626A, BUS 12A, 2SC2123, 2SD1094,++
BUY 69 B		Si-N	=BUY 69A: 800/325V		23a	TO-3	S 2530 A	23a	BU 626A, BUS 12(A), 2SC2123, 2SD1094,++
BUY 69 C		Si-N	=BUY 69A: 500/200V		23a	TO-3	S 2530 A	23a	BU 626A, BUS 12(A), 2SC2123, 2SD1094,++
BUY 70 A	Mot,Tix,Tos	Si-N	S P, TV-HA, 1000/400V, 10/15A, 75W, 6MHz		23a	TO-3	S 2530 A	23a	BU 626A, BUS 12A, 2SC2123, 2SD1094,++
BUY 70 B		Si-N	=BUY 70A: 800/325V		23a	TO-3	S 2530 A	23a	BU 626A, BUS 12(A), 2SC2123, 2SD1094,++
BUY 70 C		Si-N	=BUY 70A: 500/200V		23a	TO-3	S 2530 A	23a	BU 626A, BUS 12(A), 2SC2123, 2SD1094,++
BUY 71	Hit,Tix,Tos	Si-N	TV-HA, 2200/800V, 2A, 10W(Tc=80°), sat<10V(1,5V)		23a	TO-3			BU 225, 2SC2124, 2SD621, 2SD838
BUY 72	Sie	Si-N	S P, 280/200V, 10/15A, 60W(Tc=75°), 20MHz, <1/2µs		23a	TO-3			BUW 74, BUX 17A…C, BUX 43, BUY 18, ++
BUY 73	Sie	Si-N	S P, 280/200V, 15/25A, 117W, 20MHz, <1/2,2µs		23a	TO-3			BUV 12, BUW 73, BUX 12…13, BUY 50, ++
BUY 74	Sie	Si-N	S P, 400/250V, 12/17A, 110W, 15MHz, tf<1µs		23a	TO-3			BUW 44…46, BUW 74…77, BUX 13, BUY 50++
BUY 75	Sie	Si-N	=BUY 74: 600/300V		23a	TO-3			BUS 13, BUW 45…46, BUW 75…77, BUX 48++
BUY 76	Sie	Si-N	=BUY 74: 750/350V		23a	TO-3			BUS 13, BUW 45…46, BUW 76…77, BUX 48++
BUY 77	Sie	Si-N	S P, 400/250V, 8/10A, 60W(Tc=75°), 15MHz, <1/3,7µs		23a	TO-3			BUW 24…25, BUW 34…36, BUX 15, BUX 44++
BUY 78	Sie	Si-N	=BUY 77: 600/300V		23a	TO-3			BUS 12, BUW 25, BUW 35…36, BUX 47, ++
BUY 79	Sie	Si-N	=BUY 77: 750/350V		23a	TO-3			BUS 12, BUW 26, BUW 35…36, BUX 47, ++
BUY 80	Fer	Si-N	P, 150/60V, -/5A, 10W(Tc=100°), 60MHz, 100/340ns		2a	TO-39			-
BUY 81	Fer	Si-N	P, 150/60V, -/7,5A, 12W(Tc=100°), 60MHz, 140/460ns		2a	TO-39			-
BUY 82	Fer	Si-N	P, 150/60V, -/10A, 15W(Tc=100°), 60MHz, 110/590ns		2a	TO-39			-
BUY 83	Aeg	Si-N	S P, 160/140V, 3A, 25W, 10MHz, 200/1000ns		22a	TO-66			TIP 75, 2N3441, 2SD422…423
BUY 84	Sgs	Si-N	S P, 800/300V, 15A, 100W, 500/800		23a	TO-3			BUS 13(A), BUW 45…46, BUX 48(A…C), ++
BUY 85	Sgs	Si-N	=BUY 84: 600/250V		23a	TO-3			BUS 13(A), BUW 45…46, BUX 48(A…C), ++
BUY 86	Phi	Si-N	S P, 200/100V, 7/15A, 50W(Tc=50°), 100MHz, <1/3µs		23a	TO-3			BUW 87, BUX 17…18(A…C), BUX 43…44, ++
BUY 87	Phi	Si-N	=BUY 86: 300/150V, <800/650ns		23a	TO-3			BUW 72, BUX 17…18A…C, BUX 43…44, ++
BUY 88	Phi	Si-N	=BUY 86: 350/150V		23a	TO-3			BUW 72, BUX 17…18A…C, BUX 43…44, ++
BUY 89	Phi	Si-N	S P, SMPS, 1500/800V, 6/10A, 80W(Tc=60°), 0,2/4µs		23a	TO-3			BU 706, BU 908, BUX 88, 2SD649, 2SD821++
BUY 90	Fer	Si-P	P, 150/60V, -/5A, 10W(Tc=100°), 60MHz, 160/160ns		2a	TO-39			-
BUY 91	Fer	Si-P	P, 150/60V, -/7,5A, 12W(Tc=100°), 60MHz, 140/460ns		2a	TO-39			-
BUY 92	Fer	Si-P	P, 150/60V, -/10A, 15W(Tc=100°), 60MHz, 110/590ns		2a	TO-39			-
BUY 94	Sgs	Si-N	S P, 750/300V, -/15A, 100W, tf=1µs		23a	TO-3			BUS 12(A), BUW 26, BUW 35…36, BUX 80,++
BUY 95	Sgs	Si-N	=BUY 94: 600/250V		23a	TO-3			BUS 12(A), BUW 25, BUW 35…36, BUX 80,++
BUY 96	Sgs	Si-N	=BUY 94: 450/275V		23a	TO-3			BUS 12(A), BUW 24, BUW 34…36, BUX 80,++
BUYP 52	Ucp	Si-N	S P, 120V, 5A, 50W, 10MHz		23a	TO-3			BD 245C…F, BUX 16, 2SC2908, 2SD2140,++
BUYP 53	Ucp	Si-N	S P, 80V, 5A, 50W, 10MHz		23a	TO-3			BD 245B…F, BUX 16, 2SC2908, 2SD2140,++
BUYP 54	Ucp	Si-N	S P, 40V, 5A, 50W, 10MHz		23a	TO-3			BD 245(B…F), BD 311, 2N5068…69, 2SD844

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BUZ									
BUZ 10	Phi,Sie,Tho	MOS-N-FET-e	VFET, 50/20V, 23/92A, 75W, <0,07Ω(16A), <100/185ns		17p	TO-220			BUZ 11, 2SK600, 2SK674, 2SK1417
BUZ 10 A...		MOS-N-FET-e	=BUZ 10: on<0,12Ω(6A)		17p	TO-220			BUZ 11, 2SK600, 2SK674, 2SK1417
BUZ 10(A)L	Sie	MOS-N-FET-e	=BUZ 10: LogL, 50/10V, on<0,07Ω(11,5A)		17p	TO-220			2SK942, 2SK972, 2SK1115, 2SK1910
BUZ 10 S2	Sie	MOS-N-FET-e	=BUZ 10: 60/20V, 24A		17p	TO-220			BUZ 11, 2SK600, 2SK674, 2SK1417
BUZ 11	Phi,Sie,++	MOS-N-FET-e	VFET,50/20V, 30/120A, 75W, <0,04Ω(19A), <160/270ns		17p	TO-220			BUK 456-100, BUZ 12
BUZ 11 A...		MOS-N-FET-e	=BUZ 11: 26A, on<0,055Ω(16A)		17p	TO-220			BUK 456-100, BUZ 12
BUZ 11 FI,P,S2FI	Sie,Tho	MOS-N-FET-e	=BUZ 11: Iso, 20A, 35W		17c	TO-220Iso			BUK 445-50, BUK 545-50, 2SK1214, 2SK1420
BUZ 11 AL	Sie	MOS-N-FET-e	=BUZ 11: LogL, 50/10V, 20A, 35W		17p	TO-220			2SK942, 2SK972, 2SK1115, 2SK1910,++
BUZ 11 S2	Sie,Tho	MOS-N-FET-e	=BUZ 11: 60/20V		17p	TO-220			BUK 456-100, 2SK856, 2SK1418
BUZ 12	Sie	MOS-N-FET-e	VFET, 50/20V, 42/168A, 125W, <28mΩ(32A),<300/550ns		17p	TO-220			PRFZ 42, 2SK856, 2SK1418
BUZ 12 A		MOS-N-FET-e	=BUZ 12: on<35mΩ(32A)		17p	TO-220			PRFZ 42, 2SK856, 2SK1418
BUZ 12 AL		MOS-N-FET-e	=BUZ 12: LogL, 50/10V, on<35mΩ(21A)		17p	TO-220			2SK1542, 2SK1911
BUZ 14	Phi,Sie,Tho	MOS-N-FET-e	VFET, 50/20V, 39A, 125W, <40mΩ(22A), 250/500ns		23a	TO-3			BUZ 15...16, 2SK849, 2SK857, 2SK1124,++
BUZ 15	Phi,Sie,Tho	MOS-N-FET-e	VFET, 50/20V, 45/180A, 125W, <30mΩ(29A),<180/460ns		23a	TO-3			BUK 439-60, BUZ 347, 2SK1258, 2SK1379
BUZ 15 S2		MOS-N-FET-e	=BUZ 15: 60/20V		23a	TO-3			BUK 439-60, BUZ 347, 2SK1258, 2SK1379
BUZ 16	Sie	MOS-N-FET-e	VFET, 50/20V, 48/192A, 125W, <18mΩ(40A),<290/890ns		23a	TO-3			BUK 439-60, BUZ 346, 2SK1258, 2SK1379
BUZ 17	Sie	MOS-N-FET-e	=BUZ 14: 32A, 83,3W		66b	TO-238			BUZ 18
BUZ 18	Sie	MOS-N-FET-e	=BUZ 15: 37A, 83,3W		66b				-
BUZ 20	Phi,Sie,++	MOS-N-FET-e	VFET,100/20V, 13,5/54A, 75W,<0,2Ω(8,5A),<105/185ns		17p	TO-220			IRF530, 2SK919, 2SK922, 2SK1301, 2SK1559
BUZ 21	Phi,Sie,Tho	MOS-N-FET-e	VFET, 100/20V, 21/84A, 75W, <85mΩ(13A), <115/320ns		17p	TO-220			BUZ 22, IRF 540, IRF 542, 2SK1428,++
BUZ 21 L	Sie	MOS-N-FET-e	=BUZ21: LogL, 100/10V, on<85mΩ(10,5A), <210/400ns		17p	TO-220			BUK 555-100, 2SK1116, 2SK1302, 2SK1347++
BUZ 22	Sie	MOS-N-FET-e	VFET,100/20V, 34/136A, 125W, <55mΩ(22A),<150/460ns		17p	TO-220			BUK 456-100
BUZ 23	Phi,Sie	MOS-N-FET-e	VFET, 100/20V, 10A, 78W, on<0,2Ω(6A), 80/180ns		23a	TO-3			BUZ 35, 2SK398...399, 2SK401, 2SK1529,++
BUZ 24	Phi,Sie,Tho	MOS-N-FET-e	VFET,100/20V, 32/128A, 125W, <60mΩ(20A),<170/480ns		23a	TO-3			BUZ 349, 2SK561, 2SK1429, 2SK1433
BUZ 25	Phi,Sie,Tho	MOS-N-FET-e	VFET, 100/20V, 19A, 78W, on<0,1Ω(9A), 155/920ns		23a	TO-3			BUZ 24, BUZ 36, 2SK1267
BUZ 27	Sie	MOS-N-FET-e	=BUZ 24: 26A, 83,3W		66b	TO-238			-
BUZ 28	Sie	MOS-N-FET-e	=BUZ 25: 18A, 70W		66b	TO-238			BUZ 27
BUZ 30	Phi,Sie	MOS-N-FET-e	VFET, 200/20V, 7A, 75W, on<0,75Ω(4,5A), 80/180ns		17p	TO-220			BUZ 73, 2SK477, 2SK741, 2SK1319, 2SK1667
BUZ 30 A	Sie	MOS-N-FET-e	=BUZ 30: 21/84A, 125W, on<0,13Ω(13,5A), <155/440ns		17p	TO-220			-
BUZ 31	Phi,Sie	MOS-N-FET-e	VFET,200/20V, 13,5/54A, 75W,<0,2Ω(8,5A),<100/310ns		17p	TO-220			BUK 546-200, IRF 640, IRF 642, 2SK891,++
BUZ 32	Phi,Sie,Tho	MOS-N-FET-e	VFET, 200/20V, 9,5/38A, 75W, on<4Ω(6A), <80/175ns		17p	TO-220			BUZ 31, 2SK459, 2SK890, 2SK925, 2SK1221+
BUZ 33	Phi,Sie	MOS-N-FET-e	=BUZ 30: 7,2A, 78W		23a	TO-3			BUZ 34...35, 2SK293, 2SK400, 2SK501
BUZ 34	Phi,Sie,Tho	MOS-N-FET-e	=BUZ 31: 14A, 78W		23a	TO-3			BUZ 36, 2SK901, 2SK1135, 2SK1673,++
BUZ 35	Phi,Sie	MOS-N-FET-e	=BUZ 32: 9,9A, 78W		23a	TO-3			BUZ 34, 2SK401, 2SK633
BUZ 36	Phi,Sie	MOS-N-FET-e	VFET,200/20V, 22/88A, 125W, <0,12Ω(14A),<170/560ns		23a	TO-3			BUZ 341, BUZ 350, 2SK1491, 2SK1641,++
BUZ 37	Sie	MOS-N-FET-e	VFET, 200/20V, 13A, 70W, on<0,2Ω(7A), 135/790ns		66b	TO-238			BUZ 38
BUZ 38	Sie	MOS-N-FET-e	=BUZ 36: 18A, 83,3W		66b	TO-238			-
BUZ 40	Phi,Sie	MOS-N-FET-e	VFET, 500/20V, 2,5A, 75W, on<4,5(2,5A), 100/260ns		17p	TO-220			BUZ 74, IRF 820, IRF 822, 2SK892
BUZ 40 B		MOS-N-FET-e	=BUZ 40: 8,5/34A, on=0,8Ω(5,5A), 90/340ns		17p	TO-220			IRF 840, 2SK894, 2SK1496, 2SK1574,++
BUZ 41	Phi,Sie,++	MOS-N-FET-e	VFET, 500/20V, 5A, 62,5W, on<1,1Ω(2,5A), 100/260ns		17p	TO-220	BUK 455/600A,B	17p	IRF840, IRF842, 2SK553, 2SK893, 2SK1246+
BUZ 41 A	Sie	MOS-N-FET-e	=BUZ 41: 4,5A, 75W, on<1,5Ω(3A), <90/260ns		17p	TO-220	BUK 455/600A,B	17p	IRF830, 2SK553, 2SK893, 2SK1246, 2SK1751
BUZ 42	Phi,Sie,Tho	MOS-N-FET-e	VFET, 500/20V, 4/16A, 75W, on<2Ω(2,6A), <85/450ns		17p	TO-220	BUK 455/600A,B	17p	IRF830, IRF832, 2SK553, 2SK893, 2SK1246+
BUZ 43	Phi,Sie	MOS-N-FET-e	VFET, 500/20V, 2,8A, 78W, on<4,5Ω(2,5A), 100/260ns		23a	TO-3			BUZ 44(A), BUZ 46, 2SK635,
BUZ 44(A)	Phi,Sie	MOS-N-FET-e	VFET, 500/20V, 78W, 100/260ns(2,6A) A: 5,6A, <1,1Ω(2,8A), B: 4,8A, <1,5Ω(2,5A)		23a	TO-3			BUZ 46
BUZ 45	Phi,Sie,++	MOS-N-FET-e	VFET, 500/20V, 9,6/38A, 125W, <0,6Ω(5A),<195/570ns		23a	TO-3			BUZ339, BUZ384, 2SK512, 2SK724, 2SK1753+
BUZ 45 A		MOS-N-FET-e	=BUZ 45: 8,3/33A, on<0,8Ω(5A)		23a	TO-3			›BUZ 45
BUZ 45 B		MOS-N-FET-e	=BUZ 45: 10/40A, on<0,5Ω(5A)		23a	TO-3			›BUZ 45
BUZ 45 C		MOS-N-FET-e	=BUZ 45: 450/20V, 10A, on<0,5Ω(5A), 150/550ns		23a	TO-3			›BUZ 45
BUZ 46	Phi,Sie	MOS-N-FET-e	=BUZ 41A: 4,2A, 78W		23a	TO-3			BUZ 44
BUZ 47(A)	Sie	MOS-N-FET-e	VFET, 500/20V, 70/160ns BUZ 47: 4,5A, 50W, <1,1Ω, BUZ 47A: 3,9A, 70W, <2Ω		66b	TO-238			BUZ 48
BUZ 48(A)	Sie	MOS-N-FET-e	VFET, 500/20V, 195/570ns(2,8A) BUZ 48: 7,8A, <0,6Ω(5A), BUZ 48A: 6,8A, <0,8Ω(5A)		66b	TO-238			-
BUZ 50	Phi,Sie	MOS-N-FET-e	VFET, 1000/20V, 2,8A, 62,5W, on<3,5Ω(1,4A)		17p	TO-220			BUK 456-1000, BUZ 51
BUZ 50 A		MOS-N-FET-e	=BUZ 50: 2,5/10A, 75W, on<5Ω(1,5A), <105/220ns		17p	TO-220			›BUZ 50
BUZ 50 B		MOS-N-FET-e	=BUZ 50: 2/8A, 75W, on<8Ω(1,5A), <105/220ns		17p	TO-220			›BUZ 50
BUZ 50 C		MOS-N-FET-e	=BUZ 50: 2,3/9A, 75W, on<6Ω(1,5A), <105/170ns		17p	TO-220			›BUZ 50
BUZ 51	Sie	MOS-N-FET-e	VFET,1000/20V, 3,4/13,5A, 125W,<4Ω(2,2A), 85/245ns		17p	TO-220			BUK 456-1000
BUZ 53(A,C)	Phi,Sie	MOS-N-FET-e	VFET, L, 1000V, 2,6...3A, 78W		23a	TO-3			BUZ 54(A), 2SK696
BUZ 54	Phi,Sie	MOS-N-FET-e	VFET,1000/20V, 5,1/20A, 125W, <2Ω(2,5A),<205/690ns		23a	TO-3			BUZ 357...358, 2SK1205, 2SK1359, 2SK1773+
BUZ 54 A		MOS-N-FET-e	=BUZ 54: 4,5/18A, on<2,6Ω(3,2A)		23a	TO-3			›BUZ 54
BUZ 57(A)	Sie	MOS-N-FET-e	=BUZ 50(A): 70W		66b	TO-238			BUZ 58
BUZ 58(A)	Sie	MOS-N-FET-e	=BUZ 54(A): 83,3W		66b	TO-238			-
BUZ 60	Phi,Sie,++	MOS-N-FET-e	VFET, 400/20V, 5,5/22A, 75W, <1Ω(3,5A), <105/240ns		17p	TO-220	BUK 455/600A,B	17p	BUZ41, IRF830, 2SK553, 2SK1246, 2SK1751+
BUZ 60 B		MOS-N-FET-e	=BUZ 60: 4,5A, on<1,5Ω(2,5A)		17p	TO-220	BUK 455/600A,B	17p	›BUZ 60
BUZ 61	Sie	MOS-N-FET-e	VFET, 400/20V, 12,5/50A, 150W, <0,4Ω(8A), 85/335ns		17p	TO-220			BUZ 64, 2SK1378
BUZ 61 A		MOS-N-FET-e	=BUZ 61: 11/44A, on<0,5Ω(8A)		17p	TO-220			›BUZ 61
BUZ 63(B)	Phi,Sie	MOS-N-FET-e	=BUZ 60(B): 78W		23a	TO-3			BUZ 44(A), 2SK2264
BUZ 64	Phi,Sie	MOS-N-FET-e	VFET, 400/20V, 11,5/46A, 125W, on<0,4Ω, <130/440ns		23a	TO-3			BUZ45, 2SK312, 2SK724, 2SK1488, 2SK1752+
BUZ 67	Sie	MOS-N-FET-e	=BUZ 64: 83,3W		66b	TO-238			-
BUZ 70	Sie	MOS-N-FET-e	VFET, 60/20V, 12/48A, 40W, <0,15Ω(7,5A), <70/130ns		17p	TO-220			BUZ 20, BUZ 72, 2SK428, 2SK442, 2SK672++
BUZ 70 L		MOS-N-FET-e	=BUZ 70: LogL, on<0,15Ω(6A), <105/115ns		17p	TO-220			BUK552-60, 2SK970...71, 2SK1114, 2SK1416+
BUZ 71	Phi,Sie,++	MOS-N-FET-e	VFET, 50/20V, 14/45A, 40W, on<0,1Ω(9A), <90/125ns		17p	TO-220			BUZ 10, IRF 530, 2SK888, 2SK1416,++
BUZ 71 A...		MOS-N-FET-e	=BUZ 70: 13/52A, on<0,12Ω(9A)		17p	TO-220			›BUZ 71
BUZ 71(A)F,FI,P		MOS-N-FET-e	=BUZ 71(A): Iso, 25...30W		17c	TO-220Iso			BUK 442-60, BUK 443-50, 2SK1093...91,++
BUZ 71(A)L		MOS-N-FET-e	=BUZ 70: LogL, on<0,1Ω(7A), <125/160ns		17p	TO-220			BUZ 10(A)L, BUK 552-50, 2SK971, 2SK1555+
BUZ 71 S2		MOS-N-FET-e	=BUZ 71: 60/20V		17p	TO-220			BUZ 10S2, IRF 530, 2SK888, 2SK1416,++
BUZ 72	Phi,Sie,++	MOS-N-FET-e	VFET, 100/20V, 10/40A, 40W, <0,2Ω(6A), <105/185ns		17p	TO-220			BUZ20, IRF532, 2SK918, 2SK921, 2SK1427++
BUZ 72 A...		MOS-N-FET-e	=BUZ 72: 9/36A, on<0,25Ω(6A)		17p	TO-220			›BUZ 72
BUZ 72(A)F		MOS-N-FET-e	=BUZ 72(A): Iso, 7...8A, 25W		17c	TO-220Iso			BUK443-100, BUK543-100, 2SK1261, 2SK1556
BUZ 72(A)L		MOS-N-FET-e	=BUZ 72: LogL, 100/10V, <160/200ns		17p	TO-220			2SK1300...01, 2SK1559, 2SK1561
BUZ 73	Phi,Sie++	MOS-N-FET-e	VFET, 200/20V, 7/28A, 40W, <0,4Ω(4,5A), <80/175ns		17p	TO-220			BUZ 30...32, 2SK477, 2SK741, 2SK1319
BUZ 73 A		MOS-N-FET-e	=BUZ 73: 5,5/22A, on<0,6Ω(4,5A)		17p	TO-220			›BUZ 73
BUZ 73(A)F		MOS-N-FET-e	=BUZ 73(A): Iso, =5A, 25W		17c	TO-220Iso			BUK 444-200
BUZ 73(A)L		MOS-N-FET-e	=BUZ 73: LogL, 200/10V, <110/180ns		17p	TO-220			BUK 554-200
BUZ 74	Phi,Sie,Tho	MOS-N-FET-e	VFET, 500/20V, 2,4/9,5A, 40W, <3Ω(1,5A), <72/105ns		17p	TO-220			BUZ 40, IRF 820, 2SK382, 2SK892
BUZ 74 A		MOS-N-FET-e	=BUZ 74: 2,1/8,5A, on<4Ω(1,5A)		17p	TO-220			›BUZ 74
BUZ 76	Phi,Sie++	MOS-N-FET-e	VFET, 400/20V, 3/12A, 40W, on<1,8Ω(2A), <57/115ns		17p	TO-220	BUK 455/600A,B	17p	BUZ 60, IRF 720, 2SK1244, 2SK1493,++
BUZ 76 A		MOS-N-FET-e	=BUZ 76: 2,7/11A, on<2,5Ω(2A)		17p	TO-220	BUK 455/600A,B	17p	›BUZ 76
BUZ 77 A	Sie	MOS-N-FET-e	VFET, 600/20V, 2,7/11A, 40W, <4Ω(1,7A), <52/105ns		17p	TO-220			BUZ 50, BUZ 80, 2SK513, 2SK858

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BUZ 77 B	Sie	MOS-N-FET-e	=BUZ 77A: 2,9/11,5A, on<3,5Ω(1,7A)		17p	TO-220			›BUZ 77A
BUZ 78	Phi,Sie	MOS-N-FET-e	VFET, 800/20V, 1,5/6A, 40W, on<8Ω(1A), <65/150ns		17p	TO-220			BUZ 50, BUZ 80, 2SK602, 2SK1199, 2SK1324
BUZ 80	Phi,Sie++	MOS-N-FET-e	VFET, 800/20V, 2,6/10A, 75W, <4Ω(1,5A), <105/220ns		17p	TO-220			BUZ 81, 2SK513, 2SK792, 2SK1793
BUZ 80 A		MOS-N-FET-e	=BUZ 80: 3/12A, on<3Ω(1,5A)		17p	TO-220			›BUZ 80
BUZ 80 FI,AFI		MOS-N-FET-e	=BUZ 80: Iso, 35W		17c	TO-220Iso			2SK1356, 2SK1460
BUZ 81	Sie	MOS-N-FET-e	VFET, 800/20V, 4/16A, 125W, <2,5Ω(2,8A), 80/265ns		17p	TO-220			2SK1501, 2SK1639, 2SK1643, 2SK1807
BUZ 83(A)		MOS-N-FET-e	=BUZ 80(A): 2,9A(A: 3,4A), 78W		23a	TO-3			BUZ 54(A), BUZ 84(A), BUZ 307, 2SK415,++
BUZ 84	Phi,Sie,++	MOS-N-FET-e	VFET,800V, 5,3/21A, 125W, <2Ω(3A), <155/720ns		23a	TO-3	2SK727	18p	BUZ 355…356, 2SK727, 2SK793, 2SK1760,++
BUZ 84 A		MOS-N-FET-e	=BUZ 84: 6/24A, on<1,5Ω(3A)		23a	TO-3			2SK684, 2SK1032, 2SK1614, 2SK1968,++
BUZ 88(A)	Sie	MOS-N-FET-e	=BUZ 84(A): 4,3A(A: 5A), 83,3W		66b	TO-238			-
BUZ 90	Phi,Sie++	MOS-N-FET-e	VFET,600/20V, 4,5/18A, 70W, <1,6Ω(2,8A),<105/240ns		17p	TO-220	BUK 455/600A,B	17p	BUK 455/600, 2SK1117, 2SK1402, 2SK1809++
BUZ 90 A		MOS-N-FET-e	=BUZ 90: 4/16A, on<2Ω(2,8A)		17p	TO-220	BUK 455/600A,B	17p	›BUZ 90
BUZ 91	Sie	MOS-N-FET-e	VFET, 600/20V, 8,5/34A, 150W, <0,8Ω(5A), 90/330ns		17p	TO-220			BUK 657-600
BUZ 91 A		MOS-N-FET-e	=BUZ 91: 8/32A		17p	TO-220			›BUZ 91
BUZ 92	Sie	MOS-N-FET-e	VFET, 600/20V, 3,3A, 80W, <3Ω(2A), 60/110ns		17p	TO-220			BUK 456-800, 2SK791…792, 2SK1600…01,++
BUZ 93	Sie	MOS-N-FET-e	=BUZ 92: 3,6/14,5A, on<2,5Ω(2A)		17p	TO-220			BUK 456-800, 2SK791…792, 2SK1600…01,++
BUZ 94	Sie	MOS-N-FET-e	VFET, 600/20V, 7,8/31A, 125W, <0,9Ω(5A), 130/440ns		23a	TO-3			2SK684, 2SK1032
BUZ 100	Sie	MOS-N-FET-e	VFET, 50/20V, 60/240A, 250W, <18mΩ(60A), 140/390ns		17p	TO-220			-
BUZ 171	Sie	MOS-P-FET-e	VFET, 50/20V, 8/32A, 40W, on<0,3Ω(5A), <125/165ns		17p	TO-220			2SJ122…123, 2SJ171
BUZ 172	Sie	MOS-P-FET-e	VFET,100/20V, 5,5/22A, 40W, <0,6Ω(3,7A),<125/165ns		17p	TO-220			IRF 9643, 2SJ247
BUZ 173	Sie	MOS-P-FET-e	VFET,200/20V, 3,6/14A, 40W, <1,5Ω(2,3A),125/165ns		17p	TO-220			IRF 9620, IRF 9630
BUZ 201	Sie	MOS-N-FET-e	FREDFET, 400/20V, 12,5A, 125W, <0,4Ω(8A),130/440ns		23a	TO-3			BUK 637-400
BUZ 202	Sie	MOS-N-FET-e	=BUZ 201: 11,5A, <0,5Ω(8A)		23a	TO-3			-
BUZ 205	Sie	MOS-N-FET-e	FREDFET, 400/20V, 6/24A, 75W, on<1Ω(4A), 70/160ns		17p	TO-220			BUK 655-500, BUZ 215
BUZ 206	Sie	MOS-N-FET-e	=BUZ 205: 5A, on<1,5Ω(4A)		17p	TO-220			BU 655-500, BUZ 215…216
BUZ 210	Sie	MOS-N-FET-e	FREDFET, 500/20V, 10,5/42A, 125W, on<0,6Ω(6,5A)		23a	TO-3			BUK 737-500, BUZ 384, 2SK1516
BUZ 211	Sie	MOS-N-FET-e	=BUZ 210: 9/36A, on<0,8Ω(6,5A)		23a	TO-3			BUZ 384…385, BUK 637-500, 2SK1516
BUZ 213	Sie	MOS-N-FET-e	=BUZ 210: 8,5A, 83,3W		66b	TO-238			BUZ 384
BUZ 214	Sie	MOS-N-FET-e	=BUZ 210: 7A, 83,3W		66b	TO-238			BUZ 385
BUZ 215	Sie	MOS-N-FET-e	FREDFET, 500/20V, 5/20A, 75W,<1,5Ω(3,2A), 70/160ns		17p	TO-220			BUK 655-500
BUZ 216	Sie	MOS-N-FET-e	=BUZ 215: 4,4A, on<2Ω(3,2A)		17p	TO-220			-
BUZ 220	Sie	MOS-N-FET-e	FREDFET,800/20V, 6,5A, 125W, <1,5Ω(4,2A),150/440ns		23a	TO-3			BUK 638-800, BUZ 380
BUZ 221	Sie	MOS-N-FET-e	=BUZ 220: 5,5A, <2Ω(4,2A)		23a	TO-3			BUK 638-800, BUZ 381
BUZ 230	Sie	MOS-N-FET-e	FREDFET,1000/20V, 5,5A, 125W, <2Ω(3,5A),<230/560ns		23a	TO-3			BUK 638-1000, BUZ 380
BUZ 231	Sie	MOS-N-FET-e	=BUZ 230: 4,9A, <2,6Ω(3,5A)		23a	TO-3			BUK 638-1000, BUZ 381
BUZ 255	Sie	MOS-N-FET-e	VFET, 250/20V, 13/52A, 95W, <0,24Ω(8,5A), 75/220ns		17p	TO-220			2SK2133, 2SK2256
BUZ 271	Sie	MOS-N-FET-e	VFET, 50/20V, 22/88A, 125W, <0,15Ω(14A), 150/270ns		17p	TO-220			2SJ174, 2SJ291
BUZ 272	Sie	MOS-N-FET-e	VFET, 100/20V, 15/60A, 125W,<0,3Ω(9,5A), 150/245ns		17p	TO-220			IRF 9540, IRF 9542
BUZ 305	Sie	MOS-N-FET-e	VFET, 800/20V, 7,5/30A, 150W, on<1Ω(5A), 130/530ns		18p	TO-3P			BUK 638-800, 2SK1032, 2SK1358, 2SK1502++
BUZ 307	Phi,Sie	MOS-N-FET-e	VFET, 800/20V, 3/10A, 75W, on<3Ω(2A), 70/170ns		18p	TO-3P			2SK726, 2SK792, 2SK954, 2SK1339
BUZ 308	Phi,Sie	MOS-N-FET-e	=BUZ 307: 2,6/10A, on<4Ω(2A)		18p	TO-3P			2SK726, 2SK792, 2SK954, 2SK1339
BUZ 309	Sie	MOS-N-FET-e	VFET, 1000V, 2,8A, 125W, <2Ω		18p	TO-3P			2SK696
BUZ 310	Phi,Sie	MOS-N-FET-e	VFET, 1000/20V, 2,5/10A, 75W, <5Ω(1,6A), 70/170ns		18p	TO-3P			2SK696
BUZ 311	Phi,Sie	MOS-N-FET-e	=BUZ 310: 2,3A, on<6Ω(1,6A)		18p	TO-3P			2SK696
BUZ 312	Sie	MOS-N-FET-e	VFET, 1000/20V, 6/24A, 150W, <1,5Ω(4A), 150/635ns		18p	TO-3P			2SK1120, 2SK1934
BUZ 323	Sie	MOS-N-FET-e	VFET, 400/20V, 15/60A, 170W,<0,3Ω(9,5A),<180/520ns		18p	TO-3P			BUZ 338, 2SK899, 2SK1610, 2SK1745,++
BUZ 325	Sie	MOS-N-FET-e	VFET,400/20V, 12,5/50A, 125W,<0,35Ω(8A), 120/450ns		18p	TO-3P			BUZ 338, 2SK899, 2SK1610, 2SK1745,++
BUZ 326	Sie	MOS-N-FET-e	=BUZ 325: 10,5/42A, on<0,5Ω(6,5A), 85/335ns		18p	TO-3P			BUZ 338…39, 2SK899, 2SK1610, 2SK1745,++
BUZ 330	Phi,Sie,Mot	MOS-N-FET-e	VFET, 500/20V, 9,5/38A, 125W, <0,6Ω(6A), 118/450ns		18p	TO-3P			BUZ 338…339, 2SK724, 2SK1488, 2SK1753++
BUZ 331	Phi,Sie	MOS-N-FET-e	=BUZ 330: 8/32A, on<0,8Ω(5,5A), 90/340ns		18p	TO-3P			BUZ 338…339, 2SK724, 2SK1488, 2SK1753++
BUZ 332	Sie	MOS-N-FET-e	VFET, 600/20V, 8,5/34A, 150W, <0,8Ω(5A),90/330ns		18p	TO-3P	IRFPC 50	16p	2SK1032, 2SK1358, 2SK1614, 2SK1968,++
BUZ 332 A		MOS-N-FET-e	=BUZ 332: 8/32A, on<0,9Ω(5A)		18p	TO-3P	IRFPC 50	16p	2SK1032, 2SK1358, 2SK1614, 2SK1968,++
BUZ 334	Sie	MOS-N-FET-e	VFET, 600/20V, 12/48A, 180W,<0,5Ω(7,5A), 140/570ns		18p	TO-3P			2SK1573, 2SK1723
BUZ 338	Sie	MOS-N-FET-e	VFET,500/20V, 13,5/54A, 180W,<0,4Ω(8,5A),140/570ns		18p	TO-3P			BUK 638-500, 2SK1678
BUZ 339	Sie	MOS-N-FET-e	VFET,500/20V, 11,5/46A, 170W,<0,5Ω(7,5A),105/560ns		18p	TO-3P			BUK 638-500, 2SK1678
BUZ 341	Sie	MOS-N-FET-e	VFET, 200/20V, 33/132A, 170W,<70mΩ(21A), 150/610ns		18p	TO-3P			2SK1675
BUZ 344	Sie	MOS-N-FET-e	VFET, 100/20V, 50/200A, 170W,<35mΩ(32A), 173/730ns		18p	TO-3P			2SK1381, 2SK1434
BUZ 345	Sie	MOS-N-FET-e	VFET, 100/20V, 41/164A, 150W,<45mΩ(26A), 140/560ns		18p	TO-3P			2SK1381, 2SK1434
BUZ 346	Sie	MOS-N-FET-e	VFET, 50/20V, 58/232A, 170W, <18mΩ(47A), 195/670ns		18p	TO-3P			BUK 439-60, BUK 539-60, 2SK1379, 2SK1423
BUZ 346 S2		MOS-N-FET-e	=BUZ 346: 60/20V		18p	TO-3P			›BUZ 346
BUZ 347	Phi,Sie	MOS-N-FET-e	VFET, 50/20V, 45/180A, 125W, <30mΩ(29A), 120/360ns		18p	TO-3P			BUK 439-60, 2SK857, 2SK1124, 2SK1665,++
BUZ 348	Phi,Sie	MOS-N-FET-e	=BUZ 347: 39A, on<30mΩ(26A)		18p	TO-3P			BUK 439-60, 2SK857, 2SK1124, 2SK1665,++
BUZ 349	Phi,Sie	MOS-N-FET-e	VFET, 100/20V, 32/128A, 125W,<60mΩ(21A), 110/370ns		18p	TO-3P			2SK850…51, 2SK906, 2SK1429, 2SK1433,++
BUZ 350	Phi,Sie	MOS-N-FET-e	=BUZ 36:		18p	TO-3P			BUZ 341, 2SK623, 2SK901…902, 2SK1491,++
BUZ 351	Phi,Rca;Sie	MOS-N-FET-e	VFET, 400/20V, 11,5A, 125W, <0,4Ω(5,5A), 130/440ns		18p	TO-3P			BUZ 325…326, BUZ 338…339, 2SK1616,++
BUZ 353	Sie,Tho	MOS-N-FET-e	VFET, 500/20V, 9,5A, <0,6Ω(5,5A), 125W, 130/440ns		18p	TO-3P			BUZ 330, BUZ 338…339, 2SK724, 2SK1785++
BUZ 354	Sie,Sgs	MOS-N-FET-e	=BUZ 353: 8A, <0,8Ω(5,5A)		18p	TO-3P			BUZ 331, BUZ 338…339, 2SK724, 2SK1785++
BUZ 355	Mot,Phi,Sie	MOS-N-FET-e	VFET, 800/20V, 6/21A, 125W, <1,5Ω(3A), 150/440ns		18p	TO-3P	2SK727	18p	BUZ 305, 2SK1032, 2SK1649, 2SK1794,++
BUZ 356	Phi,Sie	MOS-N-FET-e	=BUZ 355: 5/21A, on<2Ω(3A)		18p	TO-3P	2SK727	18p	2SK727, 2SK1649, 2SK1760, 2SK1794,++
BUZ 357	Phi,Sie	MOS-N-FET-e	VFET, 1000/20V, 5,1/20A, 125W,<2Ω(3,2A), 130/530ns		18p	TO-3P			BUZ 312, 2SK1205, 2SK1359, 2SK1773,++
BUZ 358	Phi,Sie	MOS-N-FET-e	=BUZ 357: 4,5/18A, on<2,6Ω(3,2A)		18p	TO-3P			BUZ 312, 2SK1205, 2SK1359, 2SK1773,++
BUZ 360	Sie	MOS-N-FET-e	FREDFET, 800/20V, 3,6A, 75W, <3Ω(2,3A), 80/160ns		18p	TO-3P			BUZ 380…381
BUZ 361	Sie	MOS-N-FET-e	=BUZ 360: 2,9A, <4,5Ω(2,3A)		18p	TO-3P			BUZ 380…381
BUZ 376	Sie	MOS-N-FET-e	VFET, 800V, 6,5A, 125W, <1,5Ω		18p	TO-3P			BUZ 355, 2SK684, 2SK1032, 2SK1614,++
BUZ 377	Sie	MOS-N-FET-e	VFET, 800V, 5,5A, 125W, <2Ω		18p	TO-3P			BUZ 356, 2SK684, 2SK1032, 2SK1614,++
BUZ 380	Sie	MOS-N-FET-e	FREDFET, 1000V, 5,5/22A, 125W,<2Ω(3,5A), 230/570ns		18p	TO-3P			BUK 638-1000
BUZ 381	Sie	MOS-N-FET-e	=BUZ 380: 4,9A, on<2,6Ω(3,5A)		18p	TO-3P			BUK 638-1000
BUZ 382	Sie	MOS-N-FET-e	FREDFET, 400V, 12,5/50A, 125W,<0,4Ω(8A),<195/570ns		18p	TO-3P			BUK 637-400, BUK 638-500, 2SK1515…1516
BUZ 383	Sie	MOS-N-FET-e	=BUZ 382: 11,5A, on<0,5Ω(7,5A)		18p	TO-3P			BUK 637-400, BUK 638-500, 2SK1515…1516
BUZ 384	Phi,Sie	MOS-N-FET-e	FREDFET,500V, 10,5/42A, 125W,<0,6Ω(6,5A),195/570ns		18p	TO-3P			BUK 637-500, BUK 638-500, 2SK1516
BUZ 385	Phi,Sie	MOS-N-FET-e	=BUZ 384: 9A, on<0,8Ω(6,5A)		18p	TO-3P			BUK 637-500, BUK 638-500, 2SK1516
BV....BX									
BV		PIN-Di	=1SV233 (SMD-Marking)		35	SOT-23			›1SV233
BV		PIN-Di	=1SV247 (SMD-Marking)		35	SOT-23			›1SV247
BV		PIN-Di	=1SV247 (SMD-Marking)		35 (2mm)	SOT-323			›1SV247
BV		Si-N	=2SD1005-BV (SMD-Marking)		39	SOT-89			›2SD1005
BV 1		Si-P	=2SB624-BV1 (SMD-Marking)		35	SOT-23			›2SB624
BV 2		Si-P	=2SB624-BV2 (SMD-Marking)		35	SOT-23			›2SB624
BV 3		Si-P	=2SB624-BV3 (SMD-Marking)		35	SOT-23			›2SB624
BV 4		Si-P	=2SB624-BV4 (SMD-Marking)		35	SOT-23			›2SB624
BV 5		Si-P	=2SB624-BV5 (SMD-Marking)		35	SOT-23			›2SB624
BV 6	Die, Itt	Si-Di	Uni, kV Rr, 3kV, 0,05/0,15A, Uf<3V(0,1A)		31a	DO-15			BYX 120G, 1N5181

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BV 8	Die	Si-Di	kV Rr, 8kV, 0,35A, Uf<24V(0,35A)		31a	(21x6,3Ø)			BYX 110GP
BV 12	Die	Si-Di	kV Rr, 12kV, 0,35A, Uf<24V(0,35A)		31a	(21x6,3Ø)			-
BW		Si-P	=BCX 71RH (SMD-Marking)		35	SOT-23			›BCX 71RH
BW		Si-N	=2SD1005-BW (SMD-Marking)		39	SOT-89			›2SD1005
BW 1		Si-P	=2SB736-BW1 (SMD-Marking)		35	SOT-23			›2SB736
BW 2		Si-P	=2SB736-BW2 (SMD-Marking)		35	SOT-23			›2SB736
BW 3		Si-P	=2SB736-BW3 (SMD-Marking)		35	SOT-23			›2SB736
BW 4		Si-P	=2SB736-BW4 (SMD-Marking)		35	SOT-23			›2SB736
BW 5		Si-P	=2SB736-BW5 (SMD-Marking)		35	SOT-23			›2SB736
BX		Si-P	=BCX 71RJ (SMD-Marking)		35	SOT-23			›BCX 71RJ
BX 7667 W	Rhm	Hybrid-IC	VC, VHS HiFi Audio Processor		42				-
BX 7854 W	Rhm	Hybrid-IC	VC(VHS), HiFi Audio Signal Processor Unit		Modul				-
BXY		Si-Di	Mikrowellendioden/Micro Wave Diodes						
BY									
BY		Si-P	=2SA1200-Y (SMD-Marking)		39	SOT-89			›2SA1200
BY		Si-N	=2SC3395 (SMD-Marking)		35	SOT-23			›2SC3395
BY		Si-N	=2SC4396 (SMD-Marking)		35(2mm)	SOT-323			›2SC4396
BY		MOS-N-FET-e	=2SK1334 (SMD-Marking)		39	SOT-89			›2SK1334
BY		Si-P	=BCX 71RK (SMD-Marking)		35	SOT-23			›BCX 71RK
BY		Si-P	=KTA1660-Y (SMD-Marking)		39	SOT-89			›KTA 1660
BY 100(S)	Aeg,Phi	Si-Di	Rr, 1250V, 0,4A, Uf<1,5V(5A)		34a	DO-1	BY 133	31a	BY 127, BY 133, BY 227, G 1M, 1N4007,++
BY 101	Aei	Si-Di	Rr, 450/650V, 0,4A, Uf<1,5V(5A)		34a	DO-1	BY 133	31a	BY 126, BY 134, BY 226, 1N4005...4007, ++
BY 102	Itt	Si-Di	Rr, 750V, 0,6A		32a		BY 133	31a	BY 127, BY 133, BY 227, 1N4006...4007, ++
BY 103	Itt	Si-Di	Rr, 1300/1500V, 1A, Uf<1,3V(2A)		34a	DO-13	BY 133	31a	BY 127, BY 133, BY 227, BYX 87, EM 513++
BY 104	Itt	Si-Di	Rr, 800/1250V, 0,5A		34a	DO-13	BY 133	31a	BY 127, BY 133, BY 227, G 1M, 1N4007,++
BY 105	Aei	Si-Di	Rr, 800/1250V, 0,325A, Uf<1,5V(5A)		34a	DO-1	BY 133	31a	BY 127, BY 133, BY 227, G 1M, 1N4007,++
BY 112	Aeg	Si-Di	Rr, 400/600V, 0,7A, Uf<1,1V(2,8A)		12b	(13x15x6)	BY 133	31a	BY 126, BY 134, BY 226, 1N4004...4007,++
BY 113	Aeg	Si-Di	=BY 112: 800/1200V		12b	(13x15x6)	BY 133	31a	BY 127, BY 133, BY 227, G 1M, 1N4007,++
BY 114	Aei,Phi	Si-Di	Rr, 450/650V, 0,4A, Uf<1,5V(5A)		34a	DO-1	BY 133	31a	BY 126, BY 133, BY 226, 1N4005...4007, ++
BY 114 [Eiy]	Eiy	Si-Di	Rr, Uni, 400V, 0,1A, Uf<1,2V(0,5A)		2a	TO-18L	BA 157	31a	BA 158...159, BA 199/450, BAY 89
BY 115	Itt	Si-Di	Rr, 400/600V, 0,5A		34a	DO-13	BY 133	31a	BY 126, BY 134, BY 226, 1N4005...4007, ++
BY 116	Sie	Si-Di	Rr, 400V, 0,45A, Uf=1,3V(0,45A)		34a	DO-13	BY 133	31a	BY 126, BY 134, BY 226, 1N4005...4007, ++
BY 118	Phi	Si-Di	TV Booster-Diode, 300V, 5A, Uf<1,2V(14A)		22g	SOT-9	BY 329/1200	17k	BY 229/..., BY 223/..., BYT 08/...
BY 120	Sie	Si-Di	Rr, 400V, 0,45A, Uf=1,3V(0,45A)		34a	DO-13	BY 133	31a	BY 126, BY 134, BY 226, 1N4005...4007, ++
BY 121	Sie	Si-Di	=BY 120		34a		BY 133	31a	BY 127, BY 133, BY 227, 1N4006...4007, ++
BY 122	Phi	Si-Br	Br Rr, 60/120V, 42V~, 0,8A		42	(12x10x8)	B250C1500	8	B60C800, etc.
BY 123	Phi	Si-Br	=BY 122: 400/800V, 80V~, 0,7A		42	(12x10x8)	B250C1500	8	B400C800, etc
BY 124	Aei	Si-Di	Rr, 50/75V, 0,425A, Uf=1,4V(2A)		12b	(8x5x3mm)	1N4007	31a	BY 126, BY 135, BY 226, 1N4001...4007, ++
BY 125 [AEI]	Aei	Si-Di	Rr, 200V, 0,425A, Uf<1,3V(1,4A)		12b	(8x5x3mm)	1N4007	31a	BY 126, BY 134, BY 226, 1N4003...4007, ++
BY 125 [Philips]	Phi	Si-Di	Rr, 150V, 1A, Uf<1,5V(5A)		31a	SOD-13	1N4007	31a	BY 126, BY 135, BY 226, 1N4003...4007, ++
BY 126(M,GP,MGP)	Phi,Mot,++	Si-Di	Rr, 450/650V, 1A, Uf<1,5V(5A) GP[Gie]: DO-27, M[Gie]: DO-15, MGP[Tho]: DO-15		31a	SOD-18	BY 133	31a	BY 127, BY 134, BY 226, 2N4005...4007, ++
BY 127(M,GP)	Phi,Mot,++	Si-Di	=BY 126: 800/1250V		31a	SOD-18	BY 133	31a	BY 133, BY 227, BYX 87, EM 513, 1N4007++
BY 128 [Riz]		Si-Di	Rr, Uni, 800V, 0,2A		2c		BY 133	31a	BY 127, BY 133, BY 227, 1N4006...4007, ++
BY 130	Aei	Si-Di	Rr, 450/650V, 0,55A, Uf<1,5V(5A)		31a	DO-27	BY 133	31a	BY 126, BY 134, BY 226, 1N4005...4007, ++
BY 133(GP)	Itt,Mot,Gie	Si-Di	Rr, 1300V, 1A, Uf<1,3V(2A)	{GP[Gie]: DO-15	31a	DO-27	BY 133	31a	BY 127, BY 227, BYX 87, BYX 95, EM 513++
BY 134(GP)	Itt,Mot,Gie	Si-Di	=BY 133: 600V		31a	DO-27	BY 133	31a	BY 126...127, BY 226...227, 1N4006...07, ++
BY 135(GP)	Itt,Mot,Gie	Si-Di	=BY 133: 150V		31a	DO-27	BY 133	31a	BY 126...127, BY 226...227, 1N4003...07, ++
BY 137/....	Tho	Si-Di	Rr, Uni, 900...1300V, 1A, Uf<1,5V(3,5A)		31a	DO-29	BY 133	31a	BY 127, BY 133, BY 227, 1N4007, EM 513++
BY 138	Phi	Si-Di	Rr, contr.av., 800V, 1A, <1,5V(5A)		31a	SOD-18	BYD 33 M	31a	BYW 55...56, 1N4248...4249, 1N5062,++
BY 139	Aei	Si-Di	Rr, Uni, 450V, 0,165A, <1,2V(0,52A)		12b	(8x5x3mm)	BA 159	31a	BA 158...159, BAY 89...90, 1N4005...07, ++
BY 140(A)	Phi	Si-Di	TV kV-Rr, 15/15(A=12)kV, 2,5mA, <50V(0,1A)		31a	(40x8Ø)	BY 713	31a	BY 476, BY 609...610, BY 710...713
BY 141	Aei	Si-Di	Rr, Uni, 50V, 0,125A, <1,7V(2,5A)		12b	(8x5x3mm)	BA 159	31a	BA 157...159, BAY 18...20, 1N5606...09, ++
BY 142	Sie	Si-Di	Rr, 1000V, 1,1A, Uf<0,9V(1,1A)		31a	DO-27	BY 133	31a	BY 127, BY 133, BY 227, 1N4007, ++
BY 143	Sie	Si-Di	=BY 142: 600V		31a	DO-27	BY 133	31a	BY 126, BY 134, BY 226, 1N4006...4007, ++
BY 144	Itt	Si-Di	TV kV-Rr, 12,5/12,5kV, 2mA, Uf<30V(0,1A)		31a	(50x8Ø)	BY 713	31a	BY 209, BY 409, BY 476, BY 710...713, ++
BY 145	Itt	Si-Di	TV kV-Rr, 20/24kV, 2mA, Uf<45V(0,1A)		31a	(70x8Ø)	BY 713	31a	BY 713...714, BY 723...724
BY 147	Itt	Si-Di	TV Booster-Diode, 6/6,5kV, 0,25A, Uf<10V(0,25A)		31a	(70x8Ø)			BY 167, GA 5005
BY 151 N	Tho	Si-Di	Rr, 400/400V, 1A, Uf<1,5V(3,5A)		31a	DO-29	BY 133	31a	BY 126, BY 134, BY 226, 1N4004...4007, ++
BY 152 N	Tho	Si-Di	=BY 151N: 800/800V		31a	DO-29	BY 133	31a	BY 127, BY 133, BY 227, 1N4006...4007, ++
BY 154		Si-Di			31a				-
BY 156	Gie,Tho	Si-Di	Rr, contr.av., 800V, 0,65A, Uf<1,2V(0,65A)		31a	DO-29	BY 527	31a	BYW 55...56, 1N4248...4249, 1N5062
BY 157[Gen.Instr.]	Gie,Tho	Si-Di	Rr, contr.av., 800V, 0,3A, Uf<1,2V(0,3A)		31a	DO-29	BY 527	31a	BYW 55...56, 1N4248...4249, 1N5062
BY 157 [SSC]	Ssc	Si-Di	Rr, S, 400V, 0,4A, <300ns, Uf<1,5V(0,4A)				BYD 33 M	31a	BY 208/..., BY 231/..., BY 245/..., RGP10...
BY 157/....A	Tho	Si-Di	Rr, 200/320...1000/1600V, 0,3A, <300ns, Uf<1,8V(4A)		31a	DO-29	BYD 33 M	31a	BY 208/..., BY 231/..., BY 245/..., RGP10...
BY 157/....B	Tho	Si-Di	Rr, 200/320...1000/1600V, 0,4A, <300ns, Uf<2V(6A)		31a	DO-29	BYD 33 M	31a	BY 208/..., BY 231/..., BY 245/..., RGP10...
BY 157/....C	Tho	Si-Di	Rr, 200/320...1000/1600V, 0,6A, <300ns, Uf<2,2V(8A)		31a	DO-29	BYD 33 M	31a	BY 208/..., BY 231/..., BY 245/..., RGP10...
BY 158[Gen.Instr.]	Gen,Tho	Si-Di	Rr, contr.av., 400V, 0,65A, Uf<1,2V(0,65A)		31a	DO-29	BY 527	31a	BYW 54...56, 1N4246...4249, 1N5060...5062
BY 158 [SSC]	Ssc	Si-Di	FRr, 600V, 0,4A, Uf<1,5V(0,4A), <300ns				BYD 33 M	31a	BY 208/..., BY 231/..., BY 245/..., RGP10...
BY 159/....	Gie	Si-Br	Br Rr, 50...400V, 0,8A, Uf<1V(0,8A)		8		B500C1500	8	B50C800...B400C800, etc
BY 164	Phi, Die	Si-Br	Br Rr, 120V, 1,4/5A		33	(19x10x5)	B250C1500	8	B150C1500, etc.
BY 165(T)	Gie,Tho	Si-Di	TV Booster-Diode, 5/6kV, 0,3/3A, Uf<8V(0,5A)		(31a)	(26x8Ø)			BY 167, GA 5005
BY 166	Gie	Si-Di	=BY 165: 5/-kV		(31a)	(26x8Ø)			BY 167, GA 5005
BY 167	Aeg	Si-Di	TV Booster-Diode, 7/7,5kV, 0,25/3A, Uf<9,5V(0,25A)		31a	(70x8Ø)			GA 5005
BY 172	Gie	Si-Di	Rr, Uni, 800V, 1,4A, Uf<1,2V(1A)		31a	DO-27	BYD 33 M	31a	BY 227, BY 254...255, 1N5398...99, G 1K,++
BY 173	Gie	Si-Di	=BY 172: 600V		31a	DO-27	BYD 33 M	31a	BY 226...227, BY 253...255, 1N5397...99, ++
BY 174	Gie	Si-Di	=BY 172: 400V		31a	DO-27	BYD 33 M	31a	BY 226...227, BY 252...255, 1N5395...99, ++
BY 176	Phi	Si-Di	TV kV-Rr, 15/15kV, 2,5mA, Uf<35V(0,1A)		31a	(25x7Ø)	BY 713	31a	BY 476, BY 609...610, BY 710, BY 720
BY 177	Tho	Si-Di	Rr, Uni, 400V, 1,4/10A, Uf<1,5V(5A)		31a	DO-27	BYD 33 M	31a	BY 226...227, BY 252...255, 1N5395...99, ++
BY 178	Tho	Si-Di	=BY 177: 800V		31a	DO-27	BYD 33 M	31a	BY 227, BY 254...255, 1N5398...5399, ++
BY 179	Phi, Die	Si-Br	Br Rr, 400/800V, 1/5A		33	(19x10x5)	B500C1500	33	B400C1000
BY 182	Phi	Si-Di	TV kV-Rr, 12kV, 2,5mA, Uf<35V(0,1A)		31a		BY 713	31a	BY 209, BY 409, BY 476, BY 710, BY 720
BY 183/....	Tho	Si-Di	Rr, Uni, 50...600V, 0,2A, Uf<1,3V(0,1A)		31a	DO-7	BA 159	31a	BA 157...159, BAY 88...90, BY 204/..., ++
BY 184	Phi	Si-Di	TV-Rr, 1500/1800V,5mA		31a	SOD-34	BY 203/20	31a	BY 203/16...203/20, SHG 1,5...2
BY 185	Phi	Si-Di	kV-Rr, 35kV, 2,5/200mA, Uf<120V(0,2A)			(86x8Ø)			-
BY 186	Sgs	Si-Di	TV Booster-Diode, 150V, 5A, Uf<1,7V(5A)		2p	TO-39	BY 500/800	31a	BY 500/..., MR 822...826, RGP 50C...D
BY 187(-01)	Phi	Si-Di	TV kV-Rr, 10/11,5(-01=12)kV, 2,5mA, Uf<26V(0,1A)		31a	SOD-34	BY 713	31a	BY 209, BY 409, BY 476, BY 710, BY 720
BY 188 A	Phi	Si-Di	TV Rr, 25/50V, 1,2A, Uf<1,3V(5A)		31a	SOD-18	BYD 33 M	31a	BY 218/..., BY 258/..., RGP 15, RGP 30, ++
BY 188 B	Phi	Si-Di	TV Rr, 25/50V, 1,2A, Uf<1,3V(5A)		31a	SOD-18	BYD 33 M	31a	BY 218/..., BY 258/..., RGP 15, RGP 30, ++
BY 189	Itt	Si-Di	TV Damper-Diode, 850/900V, 4A, Uf<1,3V(3A)		32b		BY 329/1200[4]	17k	(BY 229/800, BY 277/750, BYW 19/800,++)[4]
BY 190	Itt	Si-Di	=BY 189: 650/700V		32b		BY 329/1200[4]	17k	(BY 229/600, BY 277/600, BYW 19/800,++)[4]

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BY 191/….(P)	Tho	Si-Di	FRr, 250…400V, 4A, Uf<1.2V(4A), <500ns BY 191/…P: •		32a	DO-4	BY 329/1200[4]	17k	(BY 229/…, BY 277/…, BYW 19/…,++)[4]
BY 192	Itt	Si-Di	TV FRr, 100V, 4A, Uf<1,3V(3A), <500ns		32b		BY 329/1200[4]	17k	(BY 229/200, BY 277/600, BYW 19/800,++)[4]
BY 193	Itt	Si-Di	=BY 192: 200V		32b		BY 329/1200[4]	17k	(BY 229/200, BY 277/600, BYW 19/800,++)[4]
BY 194	Itt	Si-Di	=BY 192: 400V		32b		BY 329/1200[4]	17k	(BY 229/400, BY 277/600, BYW 19/800,++)[4]
BY 195	Itt	Si-Di	=BY 192: 800V		32b		BY 329/1200[4]	17k	(BY 229/800, BY 277/750, BYW 19/800,++)[4]
BY 196	Itt,Mot,Tho	Si-Di	TV FRr, 100V, 1.2A, Uf<1,3V(3A), <500ns		31a	DO-27	BYD 33 M	31a	BY 201/2, BYX 58/100, MR 811, RGP 10B,++
BY 197	Itt,Mot,Tho	Si-Di	=BY 196: 200V		31a	DO-27	BYD 33 M	31a	BY 201/2, BYX 58/200, MR 812, RGP 10D,++
BY 198	Itt,Mot,Tho	Si-Di	=BY 196: 400V		31a	DO-27	BYD 33 M	31a	BY 201/4, BYX 58/400, MR 814, RGP 10G,++
BY 199	Itt,Mot,Tho	Si-Di	=BY 196: 800V		31a	DO-27	BYD 33 M	31a	BY 231/800, BY 245/800, MR 817, RGP 10K
BY 200	Itt,Mot,Tho	Si-Di	=BY 196: 1200V		31a	DO-27	(BYD 33 M)[7]	31a	BY 231/1200, BY 245/1200, BY 400
BY 201/2…./6	Aeg,Tho	Si-Di	TV Rr, 200/250…600/650V, 1/6A, Uf<1,2V(1A),<200ns		31a	DO-15	BYD 33 M	31a	BYV 13…16, RGP 10D…J, RGP 15D…J, ++
BY 202/….	Aeg	Si-Di	TV Rr,200/250…600/650V, 1,5/10A, Uf<1V(1A),<350ns		31a°	DO-15	BYD 33 M	31a	BY 218/…, BYV 95A…E, RGP 15D…J, ++
BY 203/12…/25(S)	Aeg	Si-Di	TV Rr, 1200…2500V, 0,25A, Uf<2,4V(0,2A), <300ns BY 203/…S: •		31a	DO-15 SOD-57	BY 203/20	31a	RGP 15-…, SHG 1…2.5
BY 204/….	Aeg	Si-Di	TV Rr, 400…1000V, 0,4A Uf<1,2V(0,2A), <550ns		31a	DO-15	BA 159	31a	BA 157…159, BY 208/…, RGP 10G…M, ++
BY 205/….	Tix	Si-Di	TV Rr P, 100…1000V, 3/15A, Uf<1,5V(5A), <850ns		17k	TO-220	BY 329/1200	17k	BY 229/…, BYT 71/…, RGP 80B…M
BY 206(GP)	Phi,Gie,Mot	Si-Di	TV Rr, 300/350V, 0,4A, Uf<1,5V(2A), <300ns BY 206…208GP[Gie]: •		31a	DO-14,-15 SOD-22	BA 159	31a	BA 157…159, BY 204/4, BY 406…407, ++
BY 207(GP)	Phi,Mot,Gie	Si-Di	=BY 206: 500/600V		31a	DO-14/-15	BA 159	31a	BA 158…159, BY 204/8, BY 407, ++
BY 208/….(GP)	Phi,Mot	Si-Di	TV Rr, 600…1000V, 0,75A, Uf<1.8V(2A), <350ns		31a	DO-15	BA 159	31a	BY 245/…, BY 268…269, RGP 10J…M, ++
BY 209	Phi	Si-Di	TV kV-Rr, 11,5/12,5kV, 2,5/200mA, Uf<23V(0,1A)		31a	(25x7Ø)	BY 713	31a	BY 409, BY 476, BY 509, BY 710, BY 720++
BY 210/….	Phi,Mot	Si-Di	TV Rr, 400…800V, 1/5A, Uf<1,2V(1A), <300ns		31a	SOD-22	BYD 33 M	31a	BYV 13…16, BYV 95B…E, RGP 10G…M, ++
BY 211/2…./6	Aeg	Si-Di	TV Rr, 200/250…600/650V, 2/12A, Uf<1V(1A), <350ns		12a	(27x15x6)	BY 329/1200[4]	17k	BY 218/…, BY 296…299, BYW 32…36, ++
BY 212/….R	Tho	Si-Di	TV Damper-Di, 500…750V, 4/16A, Uf<1,4V(4A),<300ns Hinlauf/Trace		32b	DO-4	BY 329/1200[4]	17k	(BY 229/800, BY 277/750, BYW 19/800,++)[4]
BY 213/….R	Tho	Si-Di	=BY 212: Rücklauf/Retrace, 600…700V		32b	DO-4	BY 329/1200[4]	17k	(BY 229/800, BY 277/750, BYW 19/800,++)[4]
BY 214/….	Tho	Si-Di	Rr, 50…1000V, 6/50A, Uf<1,2V(20A)		31a	(9x8mmØ)	BY 500/800	31a	MR 750…756
BY 215	Phi	Si-Di	2x 9kV, 0,4A, Uf<21V(5A)						-
BY 216	Phi	Si-Di	2x 9kV, 0,4A, Uf<21V(5A)						-
BY 217/….	Ssc	Si-Di	Rr, 50…400V, 1A, Uf<1,1V(1A)		31a	DO-41	BY 133	31a	BY 126, BY 134, BY 226, 1N4001…07, ++
BY 218/….	Ssc,Tho	Si-Di	FRr, 100…800V, 2/10A, Uf<1,3V(3A), <200ns		31a	DO-27	BYW 96 E	31a	BYW 33…36, BYW 16/…, RGP 30B…M, ++
BY 223	Phi	Si-Di	CTV Damper-Diode, 1500/1500V, -/5A, Uf<2,3V(20A)		26j	SOD-38	BY 359/1500[5]	17k	(BY 359/1500)[5]
BY 224/….	Phi	Si-Br	Br Rr, 400…850V, 3,2/50A, Uf<2,3V(10A)		≈33(+≈-)	(22x24x5)	B380C5000	33	B220C3200…B280C3200, etc.
BY 225/….	Phi	Si-Br	=BY 224: 100…200V		≈33(+≈-)	(22x24x5)	B80C5000	33	B80C3200…B150C3200, etc.
BY 226(GP,MGP)	Phi,Gie	Si-Di	Rr, 450/650V, 1,5/10A, Uf<1,5V(5A) BY….GP[Gie]: DO-27, BY….MGP[Gie]: DO-15		31a	SOD-18	BY 255,BYD 33M	31a	BY 259/600, GP 20J…M, 1N5396…99, ++
BY 227(GP,MGP)	Phi,Gie	Si-Di	=BY 226: 800/1250V		31a	SOD-18	BY 255,BYD 33M	31a	BY 259/1000, GP 20M, BY 350/1300, ++
BY 228/….	Aeg,Phi,++	Si-Di	TV Damper-Diode, 1000…1500V, 3/10A, Uf<1,5V(5A)		31a	SOD-64	BY 228	31a	BY 328
BY 229/….	Phi	Si-Di	TV Damper-Di,200…1000V, 7A, Uf<1,85V(20A), <450ns		17k	TO-220	BY 329/1200	17k	BY 329/…, BY 359/…, RGP 80D…M
BY 229F/….		Si-Di	=BY 229/…: Iso		17d	SOT-186	(BY 329/1200)[3]	17k	BYR 29F/…, BY 359F/…
BY 229/….R		Si-Di	=BY 229/….		17m	TO-220	(BY 329/1200)[5]	17k	(BY 329/…, BY 359/…, RGP 80D…M)[5]
BY 230	Sgs	Si-Di	750V, -/15A, <1µs		22	TO-66			-
BY 231/….	Sie	Si-Di	TV Rr, 800…1500V, 1,25A, Uf<1,7V(6A)		31a	DO-26	BY 228	31a	BY 228/…, BY 328, BY 448
BY 233/….(A)	Tho	Si-Di	P FRr, 200…600V, 10A, Uf<1,5V(8A), <150ns A=contr.av., 20W(Tc=90°)		17k	TO-220	BY 329/1200	17k	BY 329/…, RGP 80D…M
BY 238	Tsm	Si-Di	Rr, 1200/1500V, 0,8/8A, Uf<1V(0,5A)		12a	(11x11x6)	BY 133	31a	BY 350/1500, DM 513, EM 516, GP 10W…Y
BY 239/….(A)	Tho	Si-Di	P Rr, 200…1250V, 10A, Uf<1,45V(30A), A=contr.av.		17k	TO-220			BYT 12P/…
BY 239/….R		Si-Di	=BY 239:		17m	TO-220			-
BY 242	Sie	Si-Di	Rr, 800V, 0,45/6A, Uf=1,3V(0,45A)		12		BY 133	31a	BY 127, BY 133, BY 227, 1N4006…07, ++
BY 245/….	Sie	Si-Di	Rr, 800…1200V, 1,3A, Uf=0,9V(1,3A)		31a	SOD-57	BY 255,BYD 33M	31a	BY 227, BY 255, BY 350/1300, BYX 87, ++
BY 246/….	Sie	Si-Di	Rr, 600…1200V, 2,5A, Uf=0,9V(2,5A)		31a	SOD-64	BY 255	31a	BY 255, BY 259/…, BYW 17/…
BY 249/….	Phi	Si-Di	P Rr, 300…600V, 6,5A, Uf<1,6V(20A)		17k	TO-220	BY 329/1200	17k	BY229/…, BY239/…, BY359/…, GP 80G…M
BY 249F/….		Si-Di	=BY 249/…: Iso		17d	SOT-186	(BY 329/1200)[3]	17k	BY 229F/…, BY 359F/…, BYR 29F/…
BY 249/….R		Si-Di	=BY 249/…:		17m	TO-220	(BY 329/1200)[5]	17k	BY 229/…R, BY 239/…R, (GP 80G…M)[5]
BY 250	Sie	Si-Di	Rr, 1000V, 1,25/6A, Uf=1,3V(0,45A)		31a	DO-13	BY 133	31a	BY 127, BY 133, BY 227, GP 15M, 1N4007++
BY 251	Itt,Mot,Tho	Si-Di	Rr, 200V, 3/20A, Uf<1,1V(3A)		31a	DO-27A	BY 255	31a	BYW 17/200, (R)GP 30D…M, 1N5402…08, ++
BY 252	Itt,Mot,Tho	Si-Di	=BY 251: 400V		31a	DO-27A	BY 255	31a	BYW 17/400, (R)GP 30G…M, 1N5404…08, ++
BY 253	Itt,Mot,Tho	Si-Di	=BY 251: 600V		31a	DO-27A	BY 255	31a	BYW 17/600, (R)GP 30J…M, 1N5406…08, ++
BY 254	Itt,Mot,Tho	Si-Di	=BY 251: 800V		31a	DO-27A	BY 255	31a	BYW 17/800, (R)GP 30K…M, 1N5407…08, ++
BY 255	Itt,Mot,Tho	Si-Di	=BY 251: 1300V		31a	DO-27A	BY 255	31a	BY 228, BY 448, BY 458, BYW 17/1200
BY 256	Phi	Si-Br	Br Rr, 112/200V, 1.5/10A, Uf<2,1V(2A)		33(+≈-)	(19x10x5)	B250C1500	33	B80C1500, etc.
BY 257	Phi	Si-Br	=BY 256: 400/600V		33(+≈-)	(19x10x5)	B380C1500	33	B280C1500, etc.
BY 258/….	Sie	Si-Di	TV Rr, 100…800V, 1,7A, <1,5V(6A), 150ns		31a	DO-26	BYW 96 E	31a	BYV 12…16, BY 218/…, RGP 15B…M, ++
BY 259/….	Sie	Si-Di	Rr, 150…1000V, 2,4A, Uf<1,15V(6A)		31a	DO-26	RGP 30 M	31a	BY 251…255, BYW 17/…, (R)GP 30D…M, ++
BY 260/….	Phi	Si-Br	Br Rr, 200…600V, 12/20A, Uf<2V(7A)		69	(7x22mmØ)			KBPC 15-02…06
BY 261/….	Phi	Si-Br	Br Rr, 200…600V, 25/75A, Uf<2,3V(12A)		≈70	(11x28²mm)			KBPC 25-02…06
BY 268	Aeg	Si-Di	FRr, 1400/1400V, 0,8A, Uf<1,25V(0,4A), <500ns		31a	SOD-57	BY 228	31a	BY 228, BY 231/1500, BY 448
BY 269	Aeg	Si-Di	=BY 268: 1600/1600V		31a	SOD-57	(BY 228)[7]	31a	RGP 15-16, (BY 228, BY 231/1500, BY 448)[7]
BY 277/….R	Phi	Si-Di	TV Damper-Diode, 500/600…600/750V, 3/10A Uf<1,4V(10A), <400ns		26j	SOD-37	BY 329/1200[5]	17k	BYW 19/…R, BYX 71/…R, (BY 229/…R)[6]
BY 288/….	Sie	Si-Di	TV Rr, 150…1000V, 0,32A, Uf<2,8V(0,6A), 300ns		27c	(10x10x5)	BYD 33 M	31a	BY 208/…, BY 231/…, RGP 10B…M, ++
BY 289/….	Sie	Si-Di	TV Rr, 150…1000V, 0,52A, Uf<1,7V(0,6A), 300ns		27c	(10x10x5)	BYD 33 M	31a	BY 208/…, BY 231/…, RGP 10B…M, ++
BY 290/….	Sie	Si-Di	TV Rr, 150…600V, Uf<1,5V(0,6A), 150ns		27c	(10x10x5)	BYW 95 C	31a	BY 208/…, BY 231/…, RGP 10B…M, ++
BY 291/….	Sie	Si-Di	TV Rr, 75…600V, 1,1A, Uf<1,5V(6A), 150ns		27c	(10x10x5)	BYD 33 M	31a	BY 258/…, BYX 55/…, RGP 15B…M, ++
BY 292/….	Sie	Si-Di	TV Rr, 75…300V, 1,3A, Uf<1,25V(6A), 150ns		27c	(10x10x5)	BYD 33 M	31a	BY 258/…, BYX 55/…, RGP 15B…M, ++
BY 293/….	Sie	Si-Di	TV-Rr, 75…300V, 3A, Uf<1,25V, 6A), 150ns		≈28d		BY 329/1200[4]	17k	(BY 205/…, BY 229/…, BYV 87/…,++)[4]
BY 294/….	Sie	Si-Di	TV Rr, 75…600V, 2,5A, Uf<1,5V(6A), 150ns		≈28d		BY 329/1200[4]	17k	(BY 205/…, BY 229/…, BYV 87/…,++)[4]
BY 295/….	Sie	Si-Di	TV Rr, 150…600V, 1,05A, Uf<1,5V(2A), 150ns		31a	DO-15	BYD 33 M	31a	BY 258/…, BYX 55/…, RGP 15D…M, ++
BY 296(G,GP)	Itt,Mot,++	Si-Di	TV Rr, 100/200V, 2/15A, Uf<1,3V(3A), <500ns		31a	DO-27A	BYW 95 C	31a	BYW 95A…C, BY 246/600, RGP 30D…M, ++
BY 297(G,GP)	Itt,Mot,++	Si-Di	=BY 296: 200/300V		31a	DO-27A	BYW 95 C	31a	BYW 95B…C, BY 246/600, RGP 30G…M, ++
BY 298(G,GP)	Itt,Mot,++	Si-Di	=BY 296: 400/500V		31a	DO-27A	BYW 95 C	31a	BYW 95C, BY 246/600, RGP 30J…M, ++
BY 299(G,GP)	Itt,Mot,++	Si-Di	=BY 296: 800/1000V		31a	DO-27A	BYW 96 E	31a	BY 228, BY 246/1000, BYW 96E, RGP 30M,++
BY 300/….	Sie	Si-Di	TV Rr, 400…700V, 3A, Uf<1,5V(6A), 150ns			≈SOT-9	BY 329/1200[4]	17k	(BY 205/…, BY 229/…, RGP 80G…M,++)[4]
BY 302/….	Sie	Si-Di	TV Rr, 75…300V, 2,5A, Uf<1,5V(6A), 250ns		≈28d		BY 329/1200[4]	17k	(BY 205/…, BY 229/…, RGP 80B…M,++)[4]
BY 312/…	Sie	Si-Di	FRr, 75…300V, 1.7A, <250ns		31a	DO-27A	BYW 95 C	31a	BYV 12…16, BYW 95A…C, RGP 15B…M, ++
BY 318/….	Sie	Si-Di	FRr, 100…600V, 3A, Uf<1,3V(3A), <200ns		31a	DO-27A	BYW 95 C	31a	BYW 16/…, BYW 72…76, BYW 95A…C, ++
BY 328	Phi	Si-Di	TV Damper-Diode, …32kHz, 1300/1400V, 3/10A, Uf<1,45V(5A), <500ns		31a	SOD-64			-
BY 329/….	Phi	Si-Di	TV Damper-Diode, 600/800…1000/1200V, 7/80A Uf<1,85V(20A), <150ns		17k	TO-220	BY 329/1200	17k	BY 359/…, RGP 80M
BY 330	Gie,Mot	Si-Di	FRr, 50V, 1A, Uf<1,25V(1A), <750ns		31a	SOD-22	BY 228	31a	BY 201/2, BYX 55/350, RGP 10A…M, ++
BY 331	Gie,Mot	Si-Di	=BY 330: 100V		31a	SOD-22	BY 228	31a	BY 201/2, BYX 55/350, RGP 10B…M, ++

Original	Fabric.	Constr.	Info	(Compl.	Fig.		JAEGER	Fig.	International
BY 332	Gie,Mot	Si-Di	=BY 330: 200V		31a	SOD-22	BY 228	31a	BY 201/2, BYX 55/350, RGP 10D...M, ++
BY 333	Gie,Mot	Si-Di	=BY 330: 300V		31a	SOD-22	BY 228	31a	BY 201/3, BYX 55/350, RGP 10G...M, ++
BY 334	Gie,Mot	Si-Di	=BY 330: 400V		31a	SOD-22	BY 228	31a	BY 201/4, BYX 55/600, RGP 10G...M, ++
BY 335	Gie,Mot	Si-Di	=BY 330:		31a	SOD-22	BY 228	31a	BY 201/5, BYX 55/600, RGP 10J...M, ++
BY 336	Gie,Mot	Si-Di	=BY 330: 500V		31a	SOD-22	BY 228	31a	BY 201/5, BYX 55/600, RGP 10J...M, ++
BY 337	Gie,Mot	Si-Di	=BY 330: 800V		31a	SOD-22	BY 228	31a	BY 231/800, BY 245/800, RGP 10K...M, ++
BY 338	Gie,Mot	Si-Di	=BY 330: 1000V		31a	SOD-22	BY 228	31a	BY 231/1000, BY 245/1200, RGP 10M, ++
BY 339	Gie,Mot	Si-Di	=BY 330: 1500V		31a	SOD-22	BY 228	31a	BY 231/1500, BY 228, BY 448
BY 350/....	Sie	Si-Di	FRr, 1300...1500V, 1,5A, <4µs		31a	SOD-64	BY 228	31a	BY 228, BY 448
BY 359/....	Phi	Si-Di	TV FRr, 800/1000...1300/1500V, 6,5/60A, <600ns		17k	TO-220	BY 359/1500	17k	-
BY 359F/....		Si-Di	=BY 359/...: Iso	(Uf<2,3V(20A)	17d	SOT-186	(BY 359/1500)[3]	17k	-
BY 360/600	Sie	Si-Di	FRr, 600V, 1A, Uf<1,1V(1A), <400ns		31a	(7,5x40)	BYD 33 M	31a	BY 201/4, BYX 55/600, RGP 10J...M, ++
BY 396(P)	Itt,Mot,++	Si-Di	TV Rr, 100V, 3A, Uf<1,2V(5A), <500ns		31a	DO-27A	BYW 95 C	31a	BYW 95A...C, BYW 14...16/100, RGP 30B...M++
BY 397(P)	Itt,Mot,++	Si-Di	=BY 396: 200V		31a	DO-27A	BYW 95 C	31a	BYW 95A...C, BYW 14...16/200, RGP 30D...M++
BY 398(P)	Itt,Mot,++	Si-Di	=BY 396: 400V		31a	DO-27A	BYW 95 C	31a	BYW 95B...C, BYW 14...16/400, RGP 30G...M++
BY 399(P)	Itt,Mot,++	Si-Di	=BY 396: 800V		31a	DO-27A	BYW 96 E	31a	BYW 96D...E, BYW 14...16/800, RGP 30K...M++
BY 399 S	Gie	Si-Di	=BY 396: 1000V		31a	DO-27A	BYW 96 E	31a	BY 228, BY 438, BYW 96E, RGP 30M
BY 400	Mot	Si-Di	TV Rr, 1300V, 2/15A, Uf<1,3V(3A), <500ns		31a	DO-27	BY 228	31a	BY 228, BY 328, BY 448
BY 401	Mot,Tix	Si-Di	Rr, 50V, 0,5A, Uf<1,1V(0,5A)		31a	DO-7	BA 159	31a	BY 126, BY 135, BY 226, 1N4001...4007, ++
BY 402	Mot,Tix	Si-Di	=BY 401: 100V		31a	DO-7	BA 159	31a	BY 126, BY 134, BY 226, 1N4002...4007, ++
BY 403	Mot,Tix	Si-Di	=BY 401: 200V		31a	DO-7	BA 159	31a	BY 126, BY 134, BY 226, 1N4003...4007, ++
BY 404	Mot,Tix	Si-Di	=BY 401: 400V		31a	DO-7	BA 159	31a	BY 126, BY 134, BY 226, 1N4004...4007, ++
BY 405	Mot,Tix	Si-Di	=BY 401: 600V		31a	DO-7	BA 159	31a	BY 126, BY 134, BY 226, 1N4005...4007, ++
BY 406(A)	Phi,Mot	Si-Di	=BY 206: 0,8A		31a	DO-15	BYD 33 M	31a	BY 201/4, BYX 55/350, RGP 10G...M, ++
BY 407(A)	Phi,Mot	Si-Di	=BY 207: 0,8A		31a	DO-15	BYD 33 M	31a	BY 201/6, BYX 55/600, RGP 10J...M, ++
BY 409(A)	Phi	Si-Di	TV kV-Rr, 11,5/12,5kV, 2,5mA, Uf<36V(0,1A), 400ns		31a	SOD-34	BY 713	31a	BY 209, BY 509, BY 476, BY 710, BY 720++
BY 410	Itt	Si-Di	FRr, Uni, 100V, 1A, Uf<1V(1A), <100ns		31a	DO-7	BYV 27/200	31a	EGP 10B...D, FE 1A...D, BYX 92/...
BY 428	Phi	Si-Di	TV Damper-Diode, hi-def, 1300/1400V, -/4A, <500ns		31a	SOD-64			-
BY 430F/1000	Phi	Si-Di	FRr, Iso, 800/1000V, 5A, Uf<2,1V(10A), <110ns		17d	SOT-186			-
BY 431F/1000	Phi	Si-Di	=BY 430F/1000: Uf<3,15V(10A), <85ns		17d	SOT-186			-
BY 438	Phi	Si-Di	TV Damper-Di, 1200/1200V, -/5A, Uf<1,5V(5A), <1µs		31a	SOD-64	BY 228	31a	BY 228, BY 328, BY 428
BY 448	Aeg,Phi,Gie	Si-Di	TV Damper-Di, 1500/1500V, 2/8A, Uf<1,6V(3A), <20µs		31a	SOD-57	BY 228	31a	BY 228
BY 458	Aeg,Phi,Gie	Si-Di	=BY 448: 1200V		31a	SOD-57	BY 228	31a	BY 228, BY 328, BY 438
BY 459/1500	Phi	Si-Di	CRT FRr, 1500/1300V, 10/100A, <350ns, ...82kHz (f. Multi-sync Monitor)		17k	TO-220			-
BY 459F/1500		Si-Di	=BY 459/1500: Iso		17d	SOT-186			-
BY 476(A)	Phi	Si-Di	TV kV-Rr, 16/18kV, 2,5mA, Uf<44V(0,1A), 400ns		31a	(28x4mmØ)	BY 713	31a	BY 711...713, BY 721...723
BY 477	Phi	Si-Di	TV kV-Rr, 21/23kV, 2mA, Uf<50V(0,1A), 400ns		31a	(18x4mmØ)	BY 713	31a	BY 713, BY 723
BY 478	Phi	Si-Di	=BY 477: 25/27,5kV		31a	(18x4mmØ)	BY 713	31a	BY 713...714, BY 723...724
BY 500-....	Gie,Mot,Die	Si-Di	TV Rr, 100...800V, 5A, Uf<1,35V(5A), <200ns		31a	DO-27A	BY 500/800	31a	MR 821...826
BY 505	Phi	Si-Di	FRr, 2000/2200V, 0,05A, Uf<8,5V(0,1A), 200ns		31a	SOD-61	BY 203/20	31a	BY 203/20, SHG 2...2,5
BY 509	Phi	Si-Di	TV kV-Rr, 11,5/12,5kV, 4mA, <43V(0,1A), 200ns		31a	SOD-61	BY 713	31a	BY 609...610, BY 619...620, BY 718...719
BY 510	Phi	Si-Di	=BY 509: 17kV		31a	SOD-61	BY 713	31a	BY 610, BY 620
BY 520-10...-20	Gie	Si-Di	FRr, 1000...2000V, 0,5A, Uf<1,5V(0,5A), 500ns		31a	DO-41			BY 268...269, RGP 15-...
BY 527	Phi,Mot	Si-Di	Rr,contr.av., 800/1250V, 0,8/12A, Uf<1V(1A), 2,5µs		31a	SOD-57	BY 527	31a	BYW 18/1000, BYW 56, BYW 86, 1N4249
BY 530-....	Gie	Si-Di	Rr, 50...1000V, 3A, Uf<1V(1A), 5µs		31a	DO-27A	BY 255	31a	BY 251...255, BYW 17/..., 1N5400...5408, ++
BY 550-....	Fag, Die	Si-Di	Rr, 50...800V, 5/60A, Uf<1,1V(5A)		31a	DO-27A	BY 500/800	31a	BY 214/..., BY 500/..., MR 750...760
BY 584	Phi	Si-Di	TV Rr, 1500/1800V, 0,05/0,8A, Uf<8,5V(0,1A), 200ns		31a	SOD-61	BY 203/20	31a	BY 203/20, SHG 1,5...2
BY 588	Phi	Si-Di	TV Rr, Basis-Emitter-Di, 25V, 1,5/10A, Uf<1,6V(3A)		31a	SOD-57	BYW 95 C	31a	BYW 52, BYX 82, GP 15A...M, 1N5391...96,++
BY 601	Mot	Si-Di	Rr, 50V, 1,5A, Uf<1,15V(1,5A)		31a	DO-15	BY 255,BYD 33M	31a	BY 226...227, BY 251...255, 1N5391...99, ++
BY 602	Mot	Si-Di	=BY 601: 100V		31a	DO-15	BY 255,BYD 33M	31a	BY 226...227, BY 251...255, 1N5392...99, ++
BY 603	Mot	Si-Di	=BY 601: 200V		31a	DO-15	BY 255,BYD 33M	31a	BY 226...227, BY 251...255, 1N5393...99, ++
BY 604	Mot	Si-Di	=BY 601: 400V		31a	DO-15	BY 255,BYD 33M	31a	BY 226...227, BY 252...255, 1N5395...99, ++
BY 605	Mot	Si-Di	=BY 601: 600V		31a	DO-15	BY 255,BYD 33M	31a	BY 226...227, BY 253...255, 1N5397...99, ++
BY 606	Mot	Si-Di	=BY 601: 800V		31a	DO-15	BY 255,BYD 33M	31a	BY 227, BY 254...255, 1N5398...5399, ++
BY 607	Mot	Si-Di	=BY 601: 1000V		31a	DO-15	BY 255,BYD 33M	31a	BY 227, BY 255, BY 350/1300, 1N5399
BY 608	Mot	Si-Di	=BY 601: 1250V		31a	DO-15	BY 255	31a	BY 227, BY 255, BY 350/1300
BY 609	Phi	Si-Di	TV kV-Rr, 12/15kV, 4mA, Uf<50V(0,1A), 200ns		31a(9mm)	SOD-61	BY 713	31a	BY 619...620, BY 710, BY 720
BY 610	Phi	Si-Di	=BY 609: 12/17kV		31a(9mm)	SOD-61	BY 713	31a	BY 620, BY 710...711, BY 720...721
BY 614	Phi	Si-Di	FRr, 2000/2200V, 0,05/0,5A, Uf<6V(0,05A), <300ns		31a	≈SOD-57	(BY 203/20)	31a	(BY 203/20, SHG 2,5)
BY 617	Phi	Si-Di	TV kV-Rr, 7,5/9kV, 4mA, Uf<37,5V(0,1A), 100ns		31a	SOD-61	(BY 713)	31a	BY 708...709, BY 717...719
BY 619	Phi	Si-Di	TV kV-Rr, 12/15kV, 4mA, Uf<75V(0,1A), 100ns		31a	SOD-61	BY 713	31a	BY 609...610, BY 710, BY 720
BY 620	Phi	Si-Di	=BY 619: 12/17kV		31a	SOD-61	BY 713	31a	BY 610, BY 710, BY 720
BY 627	Phi	Si-Di	Impatt-Di, contr.av., 1250V, 2/20A, Uf<1,15V(3A)		31a	SOD-81			-
BY 705	Phi	Si-Di	kV-Rr, 4/5kV, 20mA, Uf<21V(0,1A), 200ns		31a(5mm)	≈SOD-61			BY 715, CY 5, HS 6
BY 706	Phi	Si-Di	=BY 705: 5/6kV		31a(5mm)	≈SOD-61			BY 716, CY 6, HS 6
BY 707	Phi	Si-Di	TV kV-Rr, 9/10kV, 4mA, Uf<52V(0,1A), 200ns		31a(9mm)	≈SOD-61	BY 713	31a	BY 609...610, BY 619...620, BY 717...719
BY 708	Phi	Si-Di	TV kV-Rr, 10/12kV, 4mA, Uf<52V(0,1A), 200ns		31a(9mm)	≈SOD-61	BY 713	31a	BY 609...610, BY 619...620, BY 718...719
BY 709	Phi	Si-Di	TV kV-Rr, 12/14kV, 4mA, Uf<52V(0,1A), 200ns		31a(9mm)	≈SOD-61	BY 713	31a	BY 609...610, BY 619...620, BY 719
BY 710	Phi	Si-Di	TV kV-Rr, 14/17kV, 3mA, Uf<70V(0,1A), 200ns		31a(11mm)	≈SOD-61	BY 713	31a	BY 610, BY 620, BY 711...714, BY 720...724
BY 711	Phi	Si-Di	TV kV-Rr, 16/19kV, 3mA, Uf<70V(0,1A), 200ns		31a(11mm)	≈SOD-61	BY 713	31a	BY 712...714, BY 721...724
BY 712	Phi	Si-Di	TV kV-Rr, 18/22kV, 3mA, Uf<76V(0,05A), 200ns		31a(12mm)	≈SOD-61	BY 713	31a	BY 713...714, BY 722...724
BY 713	Phi	Si-Di	TV kV-Rr, 20/24kV, 3mA, Uf<76V(0,05A), 200ns		31a(12mm)	≈SOD-61	BY 713	31a	BY 714, BY 723...724
BY 714	Phi	Si-Di	TV kV-Rr, 24/30kV, 3mA, Uf<76V(0,05A), 200ns		31a(12mm)	≈SOD-61			BY 724
BY 715	Phi	Si-Di	kV-Rr, 4/5kV, 20mA, Uf<28V(0,1A), 100ns		31a(5mm)	≈SOD-61			BY 705, CY 5, HS 6
BY 716	Phi	Si-Di	=BY 705: 5/6kV		31a(5mm)	≈SOD-61			BY 706, CY 6, HS 6
BY 717	Phi	Si-Di	TV kV-Rr, 9/10kV, 4mA, Uf<69V(0,1A), 100ns		31a(9mm)	≈SOD-61	BY 713	31a	BY 609...610, BY 619...620, BY 707...709
BY 718	Phi	Si-Di	TV kV-Rr, 10/12kV, 4mA, Uf<69V(0,1A), 100ns		31a(9mm)	≈SOD-61	BY 713	31a	BY 609...610, BY 619...620, BY 708...709
BY 719	Phi	Si-Di	TV kV-Rr, 12/14kV, 4mA, Uf<69V(0,1A), 100ns		31a(9mm)	≈SOD-61	BY 713	31a	BY 609...610, BY 619...620, BY 709
BY 720	Phi	Si-Di	TV kV-Rr, 14/17kV, 3mA, Uf<92V(0,1A), 100ns		31a(11mm)	≈SOD-61	BY 713	31a	BY 610, BY 620, BY 710...714
BY 721	Phi	Si-Di	TV kV-Rr, 16/19kV, 3mA, Uf<92V(0,1A), 100ns		31a(11mm)	≈SOD-61	BY 713	31a	BY 711...714
BY 722	Phi	Si-Di	TV kV-Rr, 18/22kV, 3mA, Uf<88V(0,05A), 100ns		31a(12mm)	≈SOD-61	BY 713	31a	BY 712...714
BY 723	Phi	Si-Di	TV kV-Rr, 20/24kV, 3mA, Uf<88V(0,05A), 100ns		31a(12mm)	≈SOD-61	BY 713	31a	BY 713...714
BY 724	Phi	Si-Di	TV kV-Rr, 24/30kV, 3mA, Uf<88V(0,05A), 100ns		31a(12mm)	≈SOD-61			BY 714
BY 2000	Die	Si-Di	kV Rr, 2kV, 3/20A, Uf<1,1V(3A)		31a	DO-27A			-
BY 4000	Die	Si-Di	kV Rr, 4kV, 1,5/10A, Uf<2,1V(1,5A)		31a	DO-27A			-
BY 6000	Die	Si-Di	kV Rr, 6kV, 1/6A, Uf<3,2V(1A)		31a	DO-27A			-
BYD....BYR									
BYD 11 D....M	Phi	Si-Di	Rr, contr.av., 200...1000V, 0,58A, Uf<1,2V(1A) D=200V, G=400V, J=600V, K=800V, M=1000V		31a	DO-35	BYD 33 M	31a	BYD 33D...M, BYV 26B...E, 1N4245...49
BYD 13 D....M	Phi	Si-Di	Rr, contr.av., 200...1000V, 1,4/5,5A, Uf<1,05V(1A) D=200V, G=400V, J=600V, K=800V, M=1000V		31a	SOD-81	BYD 33 M	31a	BYD 33D...M, BYW 52...56, 1N5060...5062

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BYD 14 D....M	Phi	Si-Di	Rr, contr.av., 200...1000V, 2/20A, Uf<1,15V(3A) 2,5µs, D=200V, G=400V, J=600V, K=800V, M=1000V		31a	SOD-81	BYW 96 E	31a	BYW 52...56, BYW 96D...E, 1N5060...5062,++
BYD 17 D....M	Phi	Si-Di	=BYD 14D...M: SMD		72a(3,4mm)	SOD-80			BYD 37D...M
BYD 31 D....M	Phi	Si-Di	S, contr.av., 200...1000V, 0,4A, Uf<1,15V(0,5A) <300ns, D=200V, G=400V, J=600V, K=800V, M=1000V		31a	DO-35	BYD 33 M	31a	BYD 33D...N, BYV 26B...E, BYV 95...96/...
BYD 33 D....M	Phi	Si-Di	S, contr.av., 200...1000V, 1,3/12A, Uf<1,3V(1A) <300ns, D=200V, G=400V, J=600V, K=800V, M=1000V		31a	SOD-81	BYD 33 M	31a	BYM 26A...E, BYV 36A...E, BYV 95...96/...
BYD 34 D....M	Phi	Si-Di	S, contr.av., 200...1000V, 1,8/9A, Uf<1,4V(3A) <300ns, D=200V, G=400V, J=600V, K=800V, M=1000V		31a	SOD-81	BYW 96 E	31a	BYM 26A...E, BYW 95...96/...
BYD 37 D....M	Phi	Si-Di	=BYD 33D...M: SMD		72a(3,4mm)	SOD-80			BYD 17D...M
BYD 43-20	Phi	Si-Di	kV-Rr, FLT,Strobo, 2kV, 0,64A, Uf<2,4V(1A), <300ns		31a	SOD-81			-
BYD 57 D...M	Phi	Si-Di	SMD, FRr, 200...1000V, 1A, Uf<2,1V(1A), <30...75ns D=200V, G=400V, J=600V, K=800V, M=1000V		72a(3,4mm)	SOD-80			BYD 17D...M, BYM 10-...
BYD 71 A....G	Phi	Si-Di	S,contr.av.,50...400V, 0,5/4A,Uf<1,05V(0,5A), <50ns A=50, B=100, C=150, D=200, E=250, F=300, G=400V		31a	DO-35			EGP 10A...G, FE 1A...D
BYD 73 A....G	Phi	Si-Di	S,contr.av.,50...400V, 1,75/15A,Uf<0,95V(1A), <50ns A=50, B=100, C=150, D=200, E=250, F=300, G=400V		31a	SOD-81	BYV 27/200 f. BYD 73A...D	31a	BYV 27/..., BYD 74A...G, (EGP 20A...G)
BYD 74 A....G	Phi	Si-Di	S,contr.av.,50...400V, 2,4/21A, Uf<0,94V(2A), <50ns A=50, B=100, C=150, D=200, E=250, F=300, G=400V		31a	SOD-81	BYV 27/200 f. BYD 74A...D	31a	BYV 27/..., (EGP 20A...D, FE 2A...D)
BYD 77 A....G	Phi	Si-Di	=BYD 73A...G: SMD		72a(3,4mm)	SOD-80			-
BYG 10 D....M	Aeg	Si-Di	SMD, Rr, Uni, 200...1000V, 1,5A, Uf<1,1V(1A), <5µs D=200V, G=400V, J=600V, K=800V, M=1000V		71a(5mm)				-
BYG 20 D....J	Aeg	Si-Di	SMD, FRr, 200...600V, 1,5A, Uf<1,3V(1A), <75ns D=200V, G=400V, J=600V		71a(5mm)				-
BYG 21 K....M	Aeg	Si-Di	SMD, FRr, 800...1000V, 1,5A, Uf<1,5V(1A), <120ns K=800V, M=1000V		71a(5mm)				-
BYG 22 A...D	Aeg	Si-Di	SMD, FRr, 50...200V, 2A, Uf<1,1V(2A), <25ns A=50V, B=100V, D=200V		71a(5mm)				-
BYM 05-....	Gie,Tho	Si-Di	SMD, Rr, 50...1000V, 0,5A, Uf<1,1V(0,5A)		72a(3,4mm)	SOD-80			BYD 17D...M, BYD 37D...M
BYM 06-....	Gie,Tho	Si-Di	SMD,S, 50...1000V, 0,5A, Uf<1,3V(0,5A), <150...500ns		72a(3,4mm)	SOD-80			BYD 37D...M
BYM 07-....	Gie	Si-Di	SMD, FRr, 50...400V, 0,5A, Uf<1,25V(0,5A), <50ns		72a(3,4mm)	SOD-80			BYD 77A...G
BYM 10-....	Gie,Tho	Si-Di	SMD, Rr, 50...1000V, 1A, Uf<1,1V(1A)		72a(3,4mm)	SOD-80			BYD 17D...M
BYM 11-....	Gie	Si-Di	SMD, FRr, 50...1000V, 1A, Uf<1,3V(1A), <150...500ns		72a(5mm)	MELF			-
BYM 12-....	Gie	Si-Di	SMD, FRr, 50...400V, 1A, Uf<1V(1A), <50ns		72a(5mm)	MELF			SFE 1A...H
BYM 26 A....E	Phi	Si-Di	FRr, contr.av., 200...1000V, 2,3/19A, Uf<2,65V(2A) <30...75ns, A=200V, B=400V, C=600V, D=800V, E=1000V		31a	SOD-64			BYM 36A...E
BYM 30-....	Gie	Si-Di	SMD, Rr, 50...1000V, 3A, Uf<1,1V(3A)		72a(7,5mm)				-
BYM 31-....	Gie	Si-Di	SMD, FRr, 50...1000V, 3A, Uf<1,3V(3A), <150...500ns		72a(7,5mm)				-
BYM 32-....	Gie	Si-Di	SMD, FRr, 50...400V, 3A, Uf<1V(3A), <50ns		72a(7,5mm)				-
BYM 36 A...E	Aeg, Phi	Si-Di	FRr, contr.av., 200...1000V, 3/37A, Uf<1,6V(3A) <100...150ns, A=200, B=400, C=600, D=800, E=1000V		31a	SOD-64	BYW 96 E	31a	BYW 95A...C, BYW 96D...E
BYM 56 A...E	Phi	Si-Di	Rr, contr.av., 200...1000V, 3,5/20A, Uf<1,25V(5A)		31a	SOD-64			BYW 18/..., BYW 82...86
BYP 20-...	Phi	Si-Di	Dual, 50...150V, 10A(Tc=150°), Uf<1,25V(10A), <30ns		17e	TO-220			BYQ 28/..., BYT 28/..., BYV 32/..., FE 16...
BYP 21-...	Phi	Si-Di	P Fr, 50...200V, 8A(Tc=150°), Uf<1,15V(20A), <25ns		17k	TO-220			BYW 29/..., BYW 80/..., FE 8A...J
BYP 22-...	Phi	Si-Di	Dual, 50...200V, 20A(Tc=143°), Uf<1,15V(20A), <25ns		17e	TO-220			BYV 44/..., BYW 51/...
BYP 59-...M,U	Phi	Si-Di	P, 300...400V, 60A(Tc=100°), Uf<1,4V(150A), <60ns		32a	DO-5			BYT 60/...
BYP 100	Sie	Si-Di	S P, FRED, 1000V, 5A(Tc=90°), Uf<2,45V(5A), 55ns		18k	TO-3P			-
BYP 101	Sie	Si-Di	S P, FRED, 1000V, 15A(Tc=90°), Uf<2,4V(15A), 80ns		18k	TO-3P			-
BYP 102	Sie	Si-Di	S P, FRED, 1000V, 28A(Tc=90°), Uf<2,35V(30A),130ns		18k	TO-3P			-
BYP 103	Sie	Si-Di	S P, FRED, 1000V, 45A(Tc=90°), Uf<2,35V(45A),140ns		18k	TO-3P			-
BYP 300	Sie	Si-Di	S P, FRED, 1200V, 4A(Tc=90°), Uf<3V(4A), 50ns		18k	TO-3P			-
BYP 301	Sie	Si-Di	S P, FRED, 1200V, 12A(Tc=90°), Uf<2,75V(12A), 80ns		18k	TO-3P			-
BYP 302	Sie	Si-Di	S P, FRED, 1200V, 25A(Tc=90°), Uf<2,7V(25A), 130ns		18k	TO-3P			-
BYP 303	Sie	Si-Di	S P, FRED, 1200V, 40A(Tc=90°), Uf<2,8V(40A), 140ns		18k	TO-3P			-
BYQ 27/...	Phi	Si-Di	Dual, 50...200V, 10A(Tc=118°), Uf<1,25V(10A), <20ns		≈14j	SOT-82			-
BYQ 28/...	Phi	Si-Di	Dual, 50...200V, 10A(Tc=130°), Uf<1,25V(10A), <20ns		17e	TO-220			BYP 20/..., BYV 32/..., FE 16A...J
BYQ 28F/...		Si-Di	=BYQ 28/...: Iso		17e	TO-220			BYV 32F/...
BYR 28/...	Phi	Si-Di	Dual, 500...800V, 10A(Tc=95°), Uf<2V(10A), <80ns		17e	TO-220			-
BYR 28	Phi	Si-Di	=PBYR 280CT (SMD-Marking)		≈39°	SOT-223			›PBYR 280CT
BYR 29/...	Phi,Sie	Si-Di	SMPS, 500...800V, 7,8ATc=120°), Uf<1,75V(25A),<75ns		17k	TO-220			MUR 850...8100
BYR 29	Phi	Si-Di	=PBYR 290CT (SMD-Marking)		≈39°	SOT-223			›PBYR 290CT
BYR 29F-...		Si-Di	=BYR 29/...: Iso		17d	SOT-186			-
BYR 30-...(U)	Phi,Sie	Si-Di	SMPS, 500...700V, 14A(Tc=90°), Uf<2V(50A), <100ns		32a	DO-4			BYV 31/...
BYR 34-...	Phi,Sie	Si-Di	Dual, 500...800V, 20A(Tc=105°), Uf<1,65V(30A),<80ns		17e	TO-220			BYV 44/...
BYR 79-...	Phi,Sie	Si-Di	SMPS, 500...800V, 14A(Tc=105°), Uf<2V(50A), <100ns		17k	TO-220			BYT 87/...
BYR 210	Phi	Si-Di	=PBYR 2100CT(SMD-Marking)		≈39°	SOT-223			›PBYR 2100
BYS									
BYS 05-...	Mot	Si-Di	Schottky, 20...40V, 15A(Tc=75°), Uf<0,36...0,38V(5A)		34a	≈DO-1			(BYS 15)[4]
BYS 08-...	Mot	Si-Di	Schottky, 20...50V, 8A(Tc=100°), Uf<0,5(8A)		34a	DO-17			(BYS 15)[4]
BYS 10-...	Aeg	Si-Di	SMD, Schottky, 25...45V, 1,5A, Uf<0,5V(1A)		71a(5mm)				-
BYS 11-90	Aeg	Si-Di	SMD, Schottky, 90V, 1,5A, Uf<0,9V(1A)		71a(5mm)				BYS 12-90
BYS 12-90	Aeg	Si-Di	SMD, Schottky, 90V, 1,5A, Uf<0,9V(1A)		71a(5mm)				BYS 11-90
BYS 15	Sie	Si-Di	Schottky, 45V, 15A, Uf<0,55V(15A)		32a	DO-4			BYS 31-50, BYS 32, BYV 121-45
BYS 16-...	Mot	Si-Di	Schottky, 20...40V, 15A(Tc=85°), Uf<0,38...0,42V(8A)		32a	DO-5			MBR 1520...1540, 1N5826...28
BYS 21-...	Sie	Si-Di	Schottky, 45...90V, 1A, Uf<0,55...0,9V(1A)		31a	DO-15			BYS 22-..., HRP 22, HRP 32
BYS 22-...	Sie	Si-Di	Schottky, 45...90V, 2A, Uf<0,55...0,9V(2A)		31a	(7,5x4Ø)			BYS 26-...
BYS 24-...	Sie	Si-Di	Dual, Schottky, 45...90V, 2x5A(Tc=104°), Uf<0,9(4A)		17e	TO-220			MBR 2060...20100
BYS 25-...	Mot	Si-Di	Schottky, 20...40V, 25ATc=85°), Uf<0,36...0,38V(10A)		32a	≈DO-4			BYV 121-..., MBR 2520...2540, 1N5829...31
BYS 26-...	Sie	Si-Di	Schottky, 45...90V, 3A, Uf<0,55V(3A)		31a	(7,5x6Ø)	BYS 27-45	31a	BYS 27/..., SB 350...380
BYS 27-45	Sie	Si-Di	Schottky, 45V, 5A, Uf<0,55V(5A)		31a	(7,5x4Ø)	BYS 27-45	31a	SB 550...580
BYS 28-...	Sie	Si-Di	Dual, Schottky, 45...90V, 2x15A, Uf<0,55...0,9V(10A)		18e	TO-3P			BYV 73/..., MBR 3045PT...3060PT
BYS 30	Sie	Si-Di	Schottky, 45V, 30A, Uf<0,55V(30A)		32a	≈DO-5			BYS 31/..., BYS 32, BYS 35/...
BYS 31-...	Sie	Si-Di	Schottky, 40...50V, 30A, Uf<0,63V		32a	DO-4			BYS 32, BYS 35/..., MBR 3545
BYS 32	Sie	Si-Di	=BYS 31: 50V, Uf<0,68V		32a				BYS 31/50, BYS 35/50
BYS 35-...	Mot	Si-Di	Schottky, 20...50V, 35A(Tc=90°), Uf<0,77V(70A)		32a	DO-4			BYV 22/..., MBR 3520...3545
BYS 40-...	Mot	Si-Di	Schottky, 20...40V, 40ATc=75°), Uf<0,36...0,38V(10A)		32a	DO-5			MBR 4020...4040, 1N5832...34
BYS 41(-35)	Sie	Si-Di	Schottky, 35V, 30A, Uf<0,55V(30A)		32a	DO-4			BYS 30...32, BYS 35-45, MBR 3535...3545
BYS 42(-45)	Sie	Si-Di	Dual, Schottky, 45V, 60A, Uf<0,6V(20A)		23f	TO-3			-
BYS 50	Sie	Si-Di	Schottky, 45V, 60A, Uf<0,55V(50A)		32a	≈DO-5			BYS 60-45, BYV 23/45, MBR 6045
BYS 51(-35)	Sie	Si-Di	Schottky, 35V, 60A, Uf<0,6V(60A)		32a	DO-5			BYS 50, BYS 60-45, BYV 23/45, MBR 6035
BYS 60-....	Mot	Si-Di	Schottky, 20...50V, 60A(Tc=90°), Uf<0,81(120A)		32a	DO-5			BYS 50...51, BYV 23/..., MBR 6020...6045
BYS 71-...	Sie	Si-Di	Schottky, 40...50V, 80A, Uf<0,74V		32a	DO-5			BYS 72, BYS 75/..., MBR 8045

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BYS 72	Sie	Si-Di	Schottky, 50V, 75A, Uf<0,73V		32a	DO-5			BYS 75-50, BYS 76-45, BYV 23/45, MBR7545
BYS 75-....	Mot	Si-Di	Schottky, 20...50V, 75A(Tc=90°), Uf<0,78V(150A)		32a	DO-5			BYS 71/..., BYS 72, BYS 76-45, BYV 23/...
BYS 76(-45)	Sie	Si-Di	Schottky, 45V, 75A, Uf<0,65V(75A)		32a	DO-5			BYS 71/..., BYS 72, BYS 75-45, BYV 23/45
BYS 79-...	Sie	Si-Di	Dual, Schottky, 40...50V, 30A, Uf<0,66...0,74V		23f	TO-3			BYS 42-45, MBR 3045...3060
BYS 90....99	Sie	Si-Di	Schottky Rr-Module						-
BYT									
BYT 01-....	Tho	Si-Di	FRr, 200...400V, 1A, <1,5V(1A), <50ns		31a	(6x3mmØ)	BYV 27/200	31a	BYV 26B...E, EGP 10D...G
BYT 03-....	Tho	Si-Di	S, 200...400V, 3A, Uf<1,5V(3A), <50ns		31a	DO-27A	BYV 28/200		(BYT 56G...M)
BYT 08-....	Tho	Si-Di	FRr, 200...400V, 8A(Tc=120°), Uf<1,5V(8A), <35ns		17k	TO-220			BYV 29/..., ESM 980/..., FE 8D...J
BYT 08P-....A		Si-Di	contr.av., 200...1000V, Uf<1,9V(8A), <35...65ns		17k	TO-220			-
BYT 08PI-....		Si-Di	Iso		17d	TO-220 Iso			BYQ 28F-...
BYT 11-....	Tho	Si-Di	S, 600...1000V, 1A, Uf<1,3V(1A), <100ns		31a	(6x3mmØ)			BYV 26C...E
BYT 12-....(M)	Tho	Si-Di	FRr, 200...1000V, 12A(Tc=100°), Uf<1,9V(12A), <65ns		32a	DO-4			BYT 61/..., 1N3891...3893
BYT 12P....A		Si-Di	=BYT 12-...(M): contr.av.		17k	TO-220			(BYR 79-..., BYT 87/...)
BYT 12PI....A		Si-Di	=BYT 12-...(M): Iso, 12A(Tc=50°)		17d	TO-220 Iso			-
BYT 12-....R		Si-Di	=BYT 12-...(M):		32b	DO-4			BYT 61/...R, 1N3891R...3893R
BYT 13-....	Tho	Si-Di	FRr, 600...1000V, 3A, Uf<1,3V(3A), <150ns		31a	DO-27A			BYT 56J...M
BYT 16P-...A	Tho	Si-Di	Dual, 200...400V, 16ATc=100°), Uf<1,5V(8A), <35ns		17e	TO-220			BYV 34/..., FE 16D...J, MUR 1620...1660CT
BYT 25/....	Mot	Si-Br	Br Rr, 50...1000V, 25A(Tc=55°), Uf<1,05V(40A)		70	(13x25²)			KBPC 25-005...-10
BYT 28/....	Phi	Si-Di	Dual, 300...500V, 10A(Tc=120°), Uf<1,4V(15A), <50ns		17e	TO-220			BYR 28/..., BYV 34/..., FE 16F...J
BYT 30-....(M)	Tho	Si-Di	FRr, 200...1000V, 30A(Tc=90°), Uf<1,9V(30A), <70ns		32a	DO-5			BYT 65/..., BYV 92/...
BYT 30M-400		Si-Di	=BYT 30-...(M): SMD, 30A(Tc=100°)		10-MDIP				-
BYT 30P-...		Si-Di	=BYT 30-...(M):		18k	TO-3P			-
BYT 30PI-...		Si-Di	=BYT 30P-...: Iso, 30A(Tc=60°)		18d	TO-3P Iso			-
BYT 30-...R(RM)		Si-Di	=BYT 30/...(M):		32b	DO-5			BYT 65/...R, BYV 92/...R
BYT 51 A...M	Aeg	Si-Di	Rr, 50...1000V, 1,5A, Uf<1,1V(1A), <4µs A=50, B=100, D=200, G=400, J=600, K=800, M=1000V		31a	SOD-57	BY 133	31a	BY 127, BY 133, BYW 37...43, 1N4001...07++
BYT 52 A...M	Aeg	Si-Di	FRr, 50...1000V, 1,4A, Uf<1,3V(1A), <200ns A=50, B=100, D=200, G=400, J=600, K=800, M=1000V		31a	SOD-57	BYD 33 M	31a	BY 218/..., BYV 13...16, BYV 36A...E
BYT 53 A...G	Aeg	Si-Di	FRr, 50...400V, 1,5A, Uf<1,1V(1A), <50ns A=50, B=100, C=150, D=200, F=300, G=400V		31a	SOD-57	BYV 27/... f. BYT 53A...D	31a	BYM 27..., BYV 27/..., EGP 20..., FE2...
BYT 54 A...M	Aeg	Si-Di	FRr, 50...1000V, 1,25A, Uf<1,5V(1A), <100ns A=50, B=100, D=200, G=400, J=600, K=800, M=1000V		31a	SOD-57	BYV 27/200 f. BYT 54A...D	31a	BYM 26A...E, BYV 36A...E
BYT 56 A...M	Aeg	Si-Di	FRr, 50...1000V, 3A, Uf<1,4V(3A), <100ns A=50, B=100, D=200, G=400, J=600, K=800, M=1000V		31a	SOD-64	BYV 28/200 f. BYT 56A...D	31a	BYT 13/..., BYM 36A...E, (BYW 16/...)
BYT 60-....(M)	Tho	Si-Di	FRr, 200...1000V, 60A(Tc=50°), Uf<1,9V(60A), <70ns		32a	DO-5			-
BYT 60P-...		Si-Di	=BYT 60-...: 60A(Tc=70°)		18k	TO-3P			-
BYT 60-....R,RM		Si-Di	=BYT 60-...:		32b	DO-5			-
BYT 61(B)-...(M)	Tho	Si-Di	FRr, 600...1000V, 12A(Tc=110°), Uf<1,6V(12A),<200ns BYT 61B-...: Uf<1,4V(12A)		32a	DO-4			BYT 12-..., BYX 62/..., BYX 66/...
BYT 61-...R,RM		Si-Di	=BYT 61(B)-...:		32b	DO-4			BYT 12-...R, BYX 62/...R, BYX 66/...R
BYT 62	Aeg	Si-Di	Rr, contr.av., 2400/2400V, 0,35A, Uf<3V(0,2A)		31a	SOD-57			-
BYT 65(B)-...(M)	Tho	Si-Di	FRr, 600...1000V, 30A(Tc=100°), Uf<1,6V(30A),<200ns BYT 65B-...: Uf<1,4V(30A)		32a	DO-5			BYT 30-..., BYX 64/..., BYX 67/...
BYT 65-...R,RM		Si-Di	=BYT 65(B)-...:		32b	DO-5			BYT 30-...R, BYX 64/...R, BYX 67/...R
BYT 67-....	Tho	Si-Di	FRr, 800...1000V, 50A(Tc=90°), Uf<1,5V(50A), <100ns		32a	DO-5			-
BYT 71-....	Tho	Si-Di	FRr, 100...800V, 6A(Tc=130°), Uf<1,4V(6A), <300ns		17k	TO-220	BY 329/1200	17k	BY 233/..., BYT 86/..., RGP 80B...M
BYT 71-....A		Si-Di	=BYT 71-...: contr. av.		17k	TO-220			-
BYT 71F-...		Si-Di	=BYT 71-...: Iso		17d	TO-220 Iso	(BY 329/1200)[3]	18k	BY 229F/...
BYT 71-....R		Si-Di	=BYT 71-...:		17m	TO-220	(BY 329/1200)[5]	17k	BY 229/...R
BYT 75-...K	Tho	Si-Di	P Rr, 200...600V, 120A(Tc=65°), Uf<1,4V(120A)		73a	DO-30			DS 85-02C...06C, 1N4588...4596
BYT 77	Aeg	Si-Di	FRr, 800V, 3A, Uf<1,1V(3A), <300ns		31a	SOD-64	BYW 96 E	31a	BYT 13/..., BYT 56K...M, BYW 16/800
BYT 78	Aeg	Si-Di	=BYT 77: 1000V		31a	SOD-64	BYW 96 E	31a	BYT 13/1000, BYT 56M
BYT 79/....	Phi,Sie	Si-Di	FRr, 300...500V, 10A(Tc=125°), Uf<1,4V(50A), <50ns		17k	TO-220			BYT 12/..., BYT 87/..., BYR 79/...
BYT 85/...	Aeg	Si-Di	FRr, 600...1000V, 4/20A, Uf<1,8V(4A), <80ns		17k	TO-220	BY 329/1200	17k	BY 329/..., BYR 29/..., BYT 86/...
BYT 86/...	Aeg	Si-Di	FRr, 600...1000V, 8/25A, Uf<1,8V(8A), <80ns		17k	TO-220	BY 329/1200	17k	BY 329/..., BYR 29/...
BYT 86/1300		Si-Di	=BYT 86/...: 1300V, 5/15A, Uf<1,8V(5A), <150ns		17k	TO-220	(BY 329/1200)	17k	BY 359/1300, BYT 106/1300
BYT 87/...	Aeg	Si-Di	FRr, 600...1000V, 15/30A, Uf<1,8V(15A), <80ns		17k	TO-220			BYR 79-...
BYT 106/1300	Aeg	Si-Di	FRr, 1300V, 5/15A, Uf<1,9V(5A), <120ns		17k	TO-220	(BY 329/1200)	17k	BY 359/1300, BYT 86/1300
BYT 108/...	Aeg	Si-Di	FRr, 200...400V, 8/40A, Uf<1,3V(8A), <35...50ns		17k	TO-220			BYV 29/..., FE 8D...J, RGP 80D...M
BYT 115/...	Aeg	Si-Di	FRr, 200...400V, 15/30A, Uf<1,3V(15A), <35...50ns		17k	TO-220			BYV 79/200, MUR 1520...1560
BYT 130/...		Si-Di	FRr, 600...1000V, 30A, 90ns		17k	TO-220			-
BYT 230PI(V)....	Phi,Tho	Si-Di	Dual, FRr, 200...1200V, 60A, Uf<1,9V(30A, <100ns BYT 230PI...: SOT-227B, BYT 230PIV...: SOT-227A		≈67(KAKA)	SOT-227			-
BYT 231PI(V)....	Tho	Si-Di	=BYT 230...:		≈67(KKAA)	SOT-227			-
BYT 254(V)....	Tho	Si-Di	=BYT 54...:		≈67(KKAA)	SOT-227			-
BYT 260PI(V)....	Tho	Si-Di	=BYT 261...:		≈67(KAKA)	SOT-227			-
BYT 261PI(V)....	Tho	Si-Di	Dual, FRr, 200...1000V, 2x60A, Uf<1,9V(60A, <170ns BYT 261PI...: SOT-227B, BYT 261PIV...: SOT-227A		≈67(KKAA)	SOT-227			-
BYV									
BYV 10-....(A)	Phi,Tho	Si-Di	Schottky FRr, 20...60V, 1A, Uf<0,55V(1A) , <30ns BYV 10-...A: Uf<0,45V(1A)		31a	DO-41	1N5822	31a	BYS 21/..., SB 120...180, 1N5817...5819
BYV 12	Gie,Mot	Si-Di	TV FRr, 100...1000V, 1,5/9A, Uf<1,5V(1A), <300ns		31a	SOD-57	BYD 33 M	31a	BY 218/100, BYW 32...36, RGP 15B...M ,++
BYV 13	Gie,Mot	Si-Di	=BYV 12: 400V		31a	SOD-57	BYD 33 M	31a	BY 218/400, BYW 34...36, RGP 15G...M ,++
BYV 14	Gie,Mot	Si-Di	=BYV 12: 600V		31a	SOD-57	BYD 33 M	31a	BY 218/600, BYW 36, RGP 15J...M, ++
BYV 15	Gie,Mot	Si-Di	=BYV 12: 800V		31a	SOD-57	BYD 33 M	31a	BY 218/800, BYT 77...78, RGP 15K...M, ++
BYV 16	Gie,Mot	Si-Di	=BYV 12: 1000V		31a	SOD-57	BYD 33 M	31a	BYT 78, BYV 96E, RGP 15M
BYV 18/....	Phi,Gie	Si-Di	Dual,Schottky, 30...45V, 8,8A(Tc=137°), Uf<0,6V(5a)		17e	TO-220			BYS 24/..., BYV 118/..., MBR 2060
BYV 19/....	Phi	Si-Di	Schottky, 30...45V, 9A(Tc=124°), Uf<0,6V(5A)		17k	TO-220			BYV 39/..., MBR 1035...10100
BYV 20/....	Phi	Si-Di	Schottky, 30...45V, 12,5A(Tc=124°), Uf<0,6V(15A)		32a	DO-4			BYS 15, MBR 1535...1540, 1N5827...5828
BYV 21/....	Phi	Si-Di	Schottky, 30...45V, 27A(Tc=125°), Uf<0,55V(30A)		32a	DO-4			BYS 30...32, BYV 121/..., MBR 2535...2540
BYV 22/....	Phi	Si-Di	Schottky, 30...45V, 50A(Tc=127°), Uf<0,55V(50A)		32a	DO-5			BYS 50...51, BYS 60/..., MBR 6030...6045
BYV 23/....	Phi	Si-Di	Schottky, 30...45V, 70A(Tc=116°), Uf<0,55V(70A)		32a	DO-5			BYS 71...72, BYS 75/..., BYS 76,BYV 123/...
BYV 24/....	Phi	Si-Di	FRr, 800...1000V, 12A(Tc=103), Uf<1,7V(20A),.<450ns		32a	DO-4			BYT 61/..., BYX 66/...
BYV 24/....R		Si-Di	=BYV 24:		32b	DO-4			BYT 61/...R, BYX 66/...R
BYV 25/....	Mot	Si-Br	Br Rr, 50...1000V, 25A(Tc=55°), Uf<1,1V(39A)		70	(13x25²)			KBPC 25-005...10
BYV 26(A...E)	Phi	Si-Di	FRr,contr.av.,200...1000V, 1/10A, Uf<2,5V(1A),<75ns A=200V, B=400V, C=600V, D=800V, E=1000V		31a	SOD-57	(BYD 33 M)	31a	BYV 26/B...E, BYV 36A...E, (BYD 33D...M)
BYV 27/....	Aeg,Gie,Phi	Si-Di	FRr,contr.av., 50...200V, 2/15A, Uf<1,07V(3A),<50ns		31a	SOD-57	BYV 27/200	31a	BYV 28/..., EGP 20A...G, FE 2A...D
BYV 28/....	Aeg,Gie,Phi	Si-Di	FRr,contr.av.,50...200V, 3,5/25A, Uf<1,1V(5A),<50ns		31a	SOD-64	BYV 28/200	31a	EGP 30A...G, FE 3A...D
BYV 29/....	Phi,Sie	Si-Di	FRr, 300...500V, 7,4A(Tc=125°), Uf<1,05V(5A), <50ns		17k	TO-220			BYT 08/..., BYR 29/..., FE 8F...J

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BYV 29F/....		Si-Di	=BYV 29/...: Iso		17d	SOT-186			BYR 29F/...
BYV 30/.....(M,U)	Phi,Sie,Tho	Si-Di	FRr, 200...500V, 12,5A(118°), Uf<1,05V(15A), <50ns		32a	DO-4			BYT 12/..., BYX 61/...
BYV 30/.....R,RM		Si-Di	=BYV 30/...(M,U):		32b	DO-4			BYT 12/...R, BYX 61/...R
BYV 31-....(U)	Phi,Sie	Si-Di	FRr, 300...500V, 25A(Tc=119°), Uf<1,4V(100A), <50ns		32a	DO-4			-
BYV 32/....	Phi,Sie,++	Si-Di	Dual, 50...200V, 18A(Tc=120°), Uf<1,15V(20A), <25ns		17e	TO-220			BYT 16P/...A, BYW 51/..., FE 16A...G
BYV 32D/....	Gie	Si-Di	=BYV 32/...:		17r	TO-220			-
BYV 32F/....		Si-Di	=BYV 32/...: Iso, 12A(Tc=92°)		17e	TO-220			-
BYV 32N/....	Gie	Si-Di	=BYV 32/...:		17h	TO-220			-
BYV 33/....	Phi	Si-Di	Dual, Schottky, 30...45V, 18A(Tc=124°), Uf<1V(20A)		17e	TO-220			BYV 43/..., BYV 133/..., MBR 1550...1560
BYV 33F/....		Si-Di	=BYV 33/...: Iso		17e	TO-220			BYV 43F/..., BYV 133F/...
BYV 34/....	Phi	Si-Di	Dual,300...500V, 17,5A(Tc=120°), Uf<1,4V(30A),<50ns		17e	TO-220			BYR 34/..., BYT 16P...A, FE 16F...J
BYV 36 A....E	Phi	Si-Di	contr.av.,200...1000V, 1,6/24A, Uf<1,35V(1A),<150ns A=200V, B=400V, C=600V, D=800V, E=1000V		31a	SOD-57	(BYD 33 M)	31a	BYD 34D...M, BYM 26A...E
BYV 37	Aeg	Si-Di	FRr, 800V, 2A, Uf<1,1V(1A), <300ns		31a	SOD-57	BYW 96 E	31a	BY 218/800, BYT 77...78, BYW 96D...E, ++
BYV 38	Aeg	Si-Di	=BYV 37: 1000V		31a	SOD-57	BYW 96 E	31a	BYM 26E, BYT 78, BYW 96E
BYV 39/....	Phi	Si-Di	Schottky, 30...45V, 12,5A(Tc=124°), Uf<1V(40A)		17k	TO-220			MBR 1635...1645
BYV 40-...	Phi	Si-Di	Dual, FRr, 100...200V, 1,5A, Uf<1V(1,5A), <25ns		≈39°e	SOT-223			-
BYV 42/....	Phi	Si-Di	Dual, 50...200V, 30A(Tc=104°), Uf<1,15V(30A), <25ns		17e	TO-220			-
BYV 43/....	Phi	Si-Di	Dual,Schottky,30...45V, 30A(Tc=112°), Uf<0,87V(15A)		17e	TO-220			BYV 143/..., MBR 2535CT...2545CT
BYV 43F/....		Si-Di	=BYV 43/...: Iso, 26A(Tc=49°)		17e	SOT-186			-
BYV 44/....	Phi	Si-Di	Dual, 300...500V, 26A(Tc=103°), Uf<1,4V(50A), <50ns		17e	TO-220			BYR 34/...
BYV 52/....	Phi,Tho	Si-Di	Dual, 50...200V, 2x30A(Tc=110°), Uf<1V(30A), <50ns		18e	TO-3P			-
BYV 52/...PI		Si-Di	=BYV 52/...: Iso, 2x30A(Tc=90°)		18e	TO-3P Iso			-
BYV 54(V)/....	Phi,Tho	Si-Di	Dual,50...200V, 2x50A(Tc=92°), Uf<1,25V(160A),<60ns		≈67(KAKA)	SOT-227			-
BYV 60/....	Phi	Si-Di	Dual,850...1200V, 15A(Tc=76°), Uf<2,45V(50A),<600ns		66/a	TO-238			-
BYV 61	Aeg	Si-Di	FRr, 50V, 6/30A, Uf<1V(6A), <30ns		31a	SOD-64			FE 6A...D
BYV 62	Aeg	Si-Di	=BYV 61: 100V		31a	SOD-64			FE 6B...D
BYV 63	Aeg	Si-Di	=BYV 61: 150V		31a	SOD-64			FE 6C...D
BYV 71/....	Tho	Si-Di	=BYT 71/...:		17m	TO-220			BY 229/...R
BYV 71/....R		Si-Di	=BYT 71/...R:		17	TO-220			
BYV 72/....	Phi	Si-Di	Dual, 50...200V, 30A/(Tc=105°), Uf<1,15V(30A),<28ns		18e	TO-3P			BYW99P/..., MUR3005PT...60PT, RP 30AP...MP
BYV 72F/...		Si-Di	=BYV 72/...: Iso		18e	SOT-199			BYW 77PI/..., BYW 99PI/...
BYV 73/....	Phi	Si-Di	Dual,Schottky,30...45V, 30A(Tc=112°), Uf<0,87V(30A)		18e	TO-3P			BYS 79/..., MBR 4035PT...4060PT
BYV 74-....	Phi	Si-Di	Dual, 300...500V, 30A(Tc=92°), Uf<1,6V(50A), <50ns		18e	TO-3P			MUR 3030PT...3060PT, RP 30GP...MP
BYV 74F/...		Si-Di	=BYV 74/...: Iso, 20A		18e	SOT-199			BYT 30PI/...
BYV 79/....	Phi,Sie	Si-Di	FRr, 50...200V, 12A(Tc=125°), Uf<1,3V(50A), <35ns		17k	TO-220			BYR 79/...
BYV 87/....R	Tho	Si-Di	FRr, 300...800V, 4A(Tc=100), Uf<1,4V(4A), <300ns		14m	TO-126			ESM 181/...
BYV 88/....	Phi,Tho	Si-Di	FRr, 200...1000V, 1A, Uf<1,3V, <150ns		31a	DO-29	BYD 33 M	31a	BY 218/..., BYV 37...38, RGP 10D...M, ++
BYV 92/....(M)	Phi,Gie	Si-Di	FRr, 200...500V, 35A(Tc=100°), Uf<1,4V(100A), <50ns		32a	DO-5			MR 862...866
BYV 92/....R,RM		Si-Di	=BYV 92/...:		32b	DO-5			MR 862R...866R
BYV 95 A....C	Phi,Gie	Si-Di	contr.av., 200...600V, 1,5/10A, Uf<1,6V(3A), <250ns A=200V, B=400V, C=600V		31a	SOD-57	BYD 33 M	31a	BYD 34D...M, BYW 95A...C, BYW 96D,E
BYV 96 D...E	Phi,Gie	Si-Di	=BYV 95: 800...1000V, <300ns D=800V, E=1000V		31a	SOD-57	BYD 33 M	31a	BYW 96D,E
BYV 118-....	Phi	Si-Di	Dual,Schottky,35...45V, 8,8A(Tc=138°),Uf<0,87V(10A)		17e	TO-220			BYS 24-45, BYV 33/..., BYV 133/...
BYV 118F-....		Si-Di	=BYV 118/...: Iso		17e	SOT-186			BYV 33F/..., BYV 133F/...
BYV 120-....(M)	Phi	Si-Di	Schottky, 35...45V, 13,5A(Tc=125°), Uf<0,85V(30A)		32a	DO-4			BYS 15, MBR 1535...1540, 1N2528
BYV 121-....(M)	Phi	Si-Di	Schottky, 35...45V, 27A(Tc=122°), Uf<0,83V(60A)		32a	DO-4			BYS 31-..., BYS 32, MBR 2535...40, 1N5831+
BYV 123-45	Aeg,Sie	Si-Di	Schottky, 45V, 70A(Tc=116°), Uf<0,95V(160A)		32a	DO-5			BYS 71-50, BYS 72, BYS 76-45, MBR 7545++
BYV 133-....	Phi	Si-Di	Dual,Schottky, 35...45V, 18A(Tc=121°),Uf<0,94V(20A)		17e	TO-220			BYV 33/..., BYV 133/..., MBR 2035...2045,++
BYV 133F-....		Si-Di	=BYV 133/...: Iso		17e	SOT-186			BYV 33F/..., BYV 43F/..., BYV 143F/...
BYV 143-....	Aeg,Phi,Sie	Si-Di	Dual,Schottky,35...45V, 30A(Tc=118°), Uf<0,77V(20A)		17e	TO-220			BYV 43/..., MBR 2535CT...2545CT
BYV 143F-....		Si-Di	=BYV 143/...: Iso, 18A(Tc=121°)		17e	SOT-186			BYV 43F/...
BYV 255(V)/....	Tho	Si-Di	Dual, 50...200V, 2x100A(Tc=110°), Uf<1,25V, <80ns		≈67(KKAA)	SOT-227			-
BYW									
BYW 07/....(M)	Tho	Si-Di	P FRr, 50...200V, 70A(Tc=85°), Uf<0,85V(70A), <50ns		32a	DO-5			BYT 60/..., BYW 08/..., BYW 94/...
BYW 07/....A...		Si-Di	=BYW 07/...(M,R,RM): contr.av.		32a/b	DO-5			-
BYW 07/....R,RM		Si-Di	=BYW 07/...(M):		32b	DO-5			BYT 60/...R
BYW 08/....(M)	Tho	Si-Di	P FRr, 50...200V, 80A(Tc=85°), Uf<1,05V(80A), <60ns		32a	DO-5			-
BYW 10/....	Tix	Si-Di	FRr, 50...1000V, 1,5/15A, Uf<1,4V(4A), <400ns		34a	DO-1	BYD 33 M	31a	BY 218/..., BY 258/..., RGP 15A...M, ++
BYW 10/....R		Si-Di	=BYW 10/...:		34b	DO-1	BYD 33 M	31a	BY 218/..., BY 258/..., RGP 15A...M, ++
BYW 11/....	Tix	Si-Di	P FRr, 50...1000V, 6A(Tc=25°), Uf<1,4V(6A), <400ns		32a	DO-4			BYT 61/..., BYX 50/..., BYX 66/...
BYW 11/....R		Si-Di	=BYW 11/...:		32b	DO-4			BYT 61/...R, BYX 50/...R, BYX 66/...R
BYW 12/....	Tix	Si-Di	P FRr,50...1000V, 15A(Tc=75°C), Uf<1,4V(18A),<400ns		32a	DO-4			BYX 30/...
BYW 12/....R		Si-Di	=BYW 12/...:		32b	DO-4			BYX 30/...R
BYW 13/....	Phi	Si-Di	Schottky, 25...30V, 40A(Tc=75°), Uf<0,7V(50A)		32a	DO-5			BYS 50...51, BYS 60/..., MBR 4030...4040
BYW 14/....	Tho	Si-Di	FRr, 100...800V, 3/10A, Uf<1,4V(10A), <750ns		31a	(9x8mmØ)	RGP 30 M	31a	BYT 77...78, BYW 72...76, RGP 30B...M
BYW 15/....	Tho	Si-Di	=BYW 14/...: <500ns		31a	(9x8mmØ)	BYW 96 E	31a	BYT 77...78, BYW 72...76, RGP 30B...M
BYW 16/....	Tho	Si-Di	=BYW 14/...: <200ns		31a	(9x8mmØ)	BYW 96 E	31a	BYT 56G...M, BYT 77...78, BYW 72...76
BYW 17/....	Tho	Si-Di	Rr, 100...1200V, 3/10A, Uf<1,2V(10A)		31a	(9x8mmØ)	BY 255	31a	BY 251...255, 1N5402...5408, GP 30B...M, ++
BYW 18/....	Tho	Si-Di	Rr, contr.av., 400...1000V, 3/10A, Uf<1,2V(10A)		31a	(9x8mmØ)	BYW 96 E	31a	BYW 84...86, BYW 95B,C, BYW 96D,E
BYW 19/....	Phi	Si-Di	TV Rr, 800...1000V, 7A(Tc=98°), Uf<2,3V(20A),<450ns		26h	SOD-38	(BY 329/1200)[4]	17k	(BY 229/..., RGP 80K...M)[4]
BYW 19/....R		Si-Di	=BYW 19/...:		26j	SOD-38	(BY 329/1200)[4]	17k	(BY 229/...R)[4]
BYW 20	Mot,Sie	Si-Br	Br Rr, 50V, 15A(Tc=55°)		70	(13x25²)	KBPC 1506	70	KBPC 15-005
BYW 21	Mot,Sie	Si-Br	=BYW 20: 100V		70	(13x25²)	KBPC 1506	70	KBPC 15-02
BYW 22	Mot,Sie	Si-Br	=BYW 20: 200V		70	(13x25²)	KBPC 1506	70	KBPC 15-02
BYW 23	Mot,Sie	Si-Br	=BYW 20: 300V		70	(13x25²)	KBPC 1506	70	KBPC 15-04
BYW 24	Mot,Sie	Si-Br	=BYW 20: 400V		70	(13x25²)	KBPC 1506	70	KBPC 15-04
BYW 25/....	Phi	Si-Di	FRr,800...1000V, 40A(Tc=100°), Uf<1,55V(35A),<450ns		32a	DO-5			BYT 67/...
BYW 25/....R		Si-Di	=BYW 25/...:		32b	DO-5			-
BYW 26	Mot,Sie	Si-Br	=BYW 20: 600V		70	(13x25²)	KBPC 1506	70	KBPC 15-06
BYW 27/....(GP)	Gie,Tho	Si-Di	Rr, 50...1000V, 1A, Uf<1V(1A)	{GP[Gie]: DO-41	31a	DO-15	BY 133	31a	BY 126...127, BY 133...135, 1N4001...07, ++
BYW 28	Mot,Sie	Si-Br	=BYW 20: 800V		70	(13x25²)	KBPC 1506	70	KBPC 15-08
BYW 29/....	Phi,Sie,++	Si-Di	FRr, 50...200V, 7,6A(Tc=125°), Uf<1,3(20A), <25ns		17k	TO-220			BYV 29/..., BYW 80/..., FE 8A...G
BYW 29/....A		Si-Di	=BYW 29/...: contr.av.		17k	TO-220			BYW 80/...A
BYW 29/....F		Si-Di	=BYW 29/...: Iso		17d	SOT-186			-
BYW 29M-200		Si-Di	=BYW 29/...: SMD		10-MDIP				-
BYW 30/....(U)	Gie,Mot,Phi	Si-Di	FRr, 50...200V, 10A(Tc=125°), Uf<1,3V(50A), <35ns		32a	DO-4			BYT12/..., BYV30/..., BYW81/..., BYX61/...
BYW 31/....(U)	Mot,Phi,Sie	Si-Di	FRr, 50...200V, 23A(Tc=125°), Uf<1,3V(100A), <50ns		32a	DO-4			MUR 2505...2520
BYW 32	Aeg,Gie	Si-Di	TV Rr, 200V, 2/12A, Uf<1,1V(1A), <200ns		31a	SOD-57	BYW 95 C	31a	BY218/200, BYV27/200, BYW72...76, BYW95A
BYW 33	Aeg,Gie	Si-Di	=BYW 32: 300V		31a	SOD-57	BYW 95 C	31a	BY 218/400, BYW 73...76, BYW 95B, ++
BYW 34	Aeg,Gie	Si-Di	=BYW 32: 400V		31a	SOD-57	BYW 95 C	31a	BY 218/400, BYW 74...76, BYW 95B, ++

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BYW 35	Aeg,Gie	Si-Di	=BYW 32: 500V		31a	SOD-57	BYW 95 C	31a	BY 218/600, BYW 76, BYW 95C, ++
BYW 36	Aeg,Gie	Si-Di	=BYW 32: 600V		31a	SOD-57	BYW 95 C	31a	BY 218/600, BYW 76, BYW 95C, ++
BYW 37	Gen,Gie,Sie	Si-Di	Rr, 50V, 1/8A, Uf<1,1V(1A)		31a	SOD-57	BY 133	31a	BY 126...127, BY 133...135, 1N4001...07, ++
BYW 38	Gen,Gie,Sie	Si-Di	=BYW 37: 100V		31a	SOD-57	BY 133	31a	BY 126...127, BY 133...135, 1N4002...07, ++
BYW 39	Gen,Gie,Sie	Si-Di	=BYW 37: 200V		31a	SOD-57	BY 133	31a	BY 126...127, BY 133...134, 1N4003...07, ++
BYW 40	Gen,Gie,Sie	Si-Di	=BYW 37: 400V		31a	SOD-57	BY 133	31a	BY 126...127, BY 133...134, 1N4004...07, ++
BYW 41	Gen,Gie,Sie	Si-Di	=BYW 37: 600V		31a	SOD-57	BY 133	31a	BY 126...127, BY 133...134, 1N4005...07, ++
BYW 42	Gen,Gie,Sie	Si-Di	=BYW 37: 800V		31a	SOD-57	BY 133	31a	BY 127, BY 133, BY 227, 1N4006...07, ++
BYW 43	Gen,Gie,Sie	Si-Di	=BYW 37: 1000V		31a	SOD-57	BY 133	31a	BY 127, BY 133, BY 227, 1N4007, ++
BYW 44/....	Phi	Si-Br	Br Rr, 200...800V, 4/15A						B150C5000...B600C5000, etc.
BYW 45/....	Phi	Si-Br	Br Rr, 200...800V, 6/75A						KBPC 6-02...08
BYW 46/....	Phi	Si-Br	Br Rr, 200...800V, 8/75A						KBPC 8-02...08
BYW 47/....	Phi	Si-Br	Br Rr, 200...800V, 12,5/180A						KBPC 15-02...08
BYW 48/....	Phi	Si-Di	FRr, 100...300V, 12A(Tc=100°), Uf<1,6V(20A), <200ns		32a	DO-4			BYT 12/..., BYV 30/..., 1N3890...3893, ++
BYW 48/....R		Si-Di	=BYW 48/...:		32b	DO-4			BYT 12/..., BYV 30/...R, 1N3890R...3893R,++
BYW 51-....	Mot,Tho	Si-Di	Dual, 50...200V, 2x10A(Tc=125°), Uf<0,97V(8A),<35ns		17e	TO-220			BYP 22/..., BYV 42/..., BYV 44/...
BYW 51F-...		Si-Di	=BYW 51-...: Iso		17e	TO-220 Iso			-
BYW 51M-200		Si-Di	=BYW 51-...: SMD		10-MDIP				-
BYW 52	Aeg	Si-Di	Rr, contr.av., 200V, 2/12A, Uf<1V(1A), <4µs		31a	SOD-57	BYW 95 C	31a	BYW 18/400, BYW 82...86, 1N5060...5062
BYW 53	Aeg	Si-Di	=BYW 52: 400V		31a	SOD-57	BYW 95 C	31a	BYW 18/400, BYW 83...86, 1N5060...5062
BYW 54	Aeg	Si-Di	=BYW 52: 600V		31a	SOD-57	BYW 95 C	31a	BYW 18/600, BYW 84...86, 1N5061...5062
BYW 55	Aeg	Si-Di	=BYW 52: 800V		31a	SOD-57	BYW 96 E	31a	BYW 18/800, BYW 85...86, 1N5062
BYW 56	Aeg	Si-Di	=BYW 52: 1000V		31a	SOD-57	BYW 96 E	31a	BYW 18/1000, BYW 86
BYW 58/....	Gen,Gie	Si-Di	FRr, 50...600V, 1A, Uf<1,1V(1A), <200ns		31a	SOD-57	BYD 33 M	31a	BY 201/..., BYV 12...16, RGP 10A...M, ++
BYW 59/....	Gen,Gie	Si-Di	FRr, 50...600V, 3A, Uf<1,1V(3A9, <200ns		31a	SOD-64	BYW 95 C	31a	BYW 16/..., BYW 72...76, BYW 95A...C, ++
BYW 60	Mot,Sie	Si-Br	Br Rr, 50V, 35A(Tc=55°), Uf<1,07V(47A)		70	(13x25²)			KBPC 35-005
BYW 61	Mot,Sie	Si-Br	=BYW 60: 100V		70	(13x25²)			KBPC 35-02
BYW 62	Mot,Sie	Si-Br	=BYW 60: 200V		70	(13x25²)			KBPC 35-02
BYW 63	Mot,Sie	Si-Br	=BYW 60: 300V		70	(13x25²)			KBPC 35-04
BYW 64	Mot,Sie	Si-Br	=BYW 60: 400V		70	(13x25²)			KBPC 35-04
BYW 65/....	Gen,Gie	Si-Di	Rr, 200...1000V, 1A, Uf<1,2V(1A)		31a	SOD-57	BY 133	31a	BY 126...127, BY 133...134, 1N4003...07, ++
BYW 66	Mot,Sie	Si-Br	=BYW 60: 600V		70	(13x25²)			KBPC 35-06
BYW 67/....	Gen,Gie	Si-Di	Rr, 200...800V, 3A, Uf<1,1A(3A), 5µs		31a	SOD-64	RGP 30 M	31a	BY 251...255, 1N5402...08, RGP 30D...M, ++
BYW 68	Mot,Sie	Si-Br	=BYW 60: 800V		70	(13x25²)			KBPC 35-08
BYW 69(A,B)	Tho	Si-Di	Schottky, 20(A=40, B=60)V, 15A, Uf<0,65		32a	DO-4			BYS 15, MBR 1520...1540, 1N5826...28
BYW 70(A,B)	Tho	Si-Di	Schottky, 20(A=40,B=60)V, 25A, Uf<0,65V		32a	DO-5			BYS31...32, BYS35/..., BYS41, 1N5832...34
BYW 71(A,B)	Tho	Si-Di	Schottky, 20(A=40, B=60)V, 10A, Uf<0,65V		32a	DO-4			BYS 15, BYV 120/..., MBR 1520...1540
BYW 72	Aeg,Gie	Si-Di	FRr, 200V, 3/15A, Uf<1,1V(3A), <200ns		31a	SOD-64	BYW 95 C	31a	BY318/200, BYT56G, BYW16/200, BYW95A,++
BYW 73	Aeg,Gie	Si-Di	=BYW 72: 300V		31a	SOD-64	BYW 95 C	31a	BY318/400, BYT56G, BYW16/400, BYW95B,++
BYW 74	Aeg,Gie	Si-Di	=BYW 72: 400V		31a	SOD-64	BYW 95 C	31a	BY318/400, BYT56G, BYW16/400, BYW95B,++
BYW 75	Aeg,Gie	Si-Di	=BYW 72: 500V		31a	SOD-64	BYW 95 C	31a	BY318/600, BYT56J, BYW16/600, BYW95C,++
BYW 76	Aeg,Gie	Si-Di	=BYW 72: 600V		31a	SOD-64	BYW 95 C	31a	BY318/600, BYT56J, BYW16/800, BYW95C,++
BYW 77-...(M)	Mot,Tho	Si-Di	FRr, 50...200V, 25A(Tc=125°), Uf<1,1V(63A), <50ns		32a	DO-4			BYV 31/..., BYW 31/..., MUR 2505...2520
BYW 77-...A...		Si-Di	=BYW 77-...(M,R,RM): contr.av.		32a/b	DO-4			-
BYW 77M-200		Si-Di	=BYW 77-...: SMD		10-MDIP				-
BYW 77P-...		Si-Di	=BYW 77-...:		18k	TO-3P			BYT 30P-...
BYW 77PI-...		Si-Di	=BYW 77P-.: Iso, 25A(Tc=100°)		18d	TO-3P Iso			BYT 30PI-...
BYW 77-...R(RM)		Si-Di	=BYW 77-.:		32b	DO-4			-
BYW 78-...(M)	Mot,Tho	Si-Di	FRr, 50...200V, 50A(Tc=100°), Uf<1,1V(160A), <60ns		32a	DO-5			BYW 07/...(M), BYW 93/..., BYW 94/...
BYW 78-...A...		Si-Di	=BYW 78-...(M,R,RM): contr.av.		32a/b	DO-5			BYW 07/...A...
BYW 78-....R(RM)		Si-Di	=BYW 78-...:		32b	DO-5			BYW 07/...R(RM
BYW 79	Mot	Si-Br	Br Rr, 1000V, 15A(Tc=55°), Uf<1V(24A)		70	(13x25²)			KBPC 15-10
BYW 80-...	Mot,Tho	Si-Di	FRr, 50...200V, 10A(Tc=120°), Uf<1,25V(22A), <35ns		17k	TO-220			BYP 21-..., BYW 29/..., FE 8A...G
BYW 80-...A		Si-Di	=BYW 80/...: contr.av.		17k	TO-220			-
BYW 80F-...		Si-Di	=BYW 80P-...: Iso, 10A(Tc=95°)		17d	TO-220 Iso			BYW 29/...F
BYW 80PI-...		Si-Di	=BYW 80P-...: Iso, 10A(Tc=110°)		17d	TO-220 Iso			BYW 29/...F
BYW 81-...(M)	Mot,Tho	Si-Di	FRr, 50...200V, 15A(Tc=120°), Uf<1,25V(38A), <35ns		32a	DO-4			BYV 31/..., BYW 31/..., BYW 77/...(M)
BYW 81-...A...		Si-Di	=BYW 81-...(M,R,RM): contr.av.		32a/b	DO-4			BYW 77/...A...
BYW 81M-200		Si-Di	=BYW 81-...: SMD		10-MDIP				-
BYW 81P-...		Si-Di	=BYW 81P-...(M):		17k	TO-220			BYV 79/..., MUR 1505...1560
BYW 81PI-...		Si-Di	BYW 81P-...: Iso, 15A(90°)		17d	TO-220 Iso			-
BYW 81-....R,RM		Si-Di	=BYW 81-...:		32b	DO-4			BYW 77/...R(RM)
BYW 82	Aeg	Si-Di	Rr, contr.av. 200V, 3/18A, Uf<1V(3A), <4µs		31a	SOD-64	BYW 95 C	31a	BYM 56A, BYW 18/400, BYW 95A
BYW 83	Aeg	Si-Di	=BYW 82: 400V		31a	SOD-64	BYW 95 C	31a	BYM 56B, BYW 18/400, BYW 95B
BYW 84	Aeg	Si-Di	=BYW 82: 600V		31a	SOD-64	BYW 95 C	31a	BYM 56C, BYW 18/600, BYW 95C
BYW 85	Aeg	Si-Di	=BYW 82: 800V		31a	SOD-64	BYW 96 E	31a	BYM 56D, BYW 18/800, BYW 96D
BYW 86	Aeg	Si-Di	=BYW 82: 1000V		31a	SOD-64	BYW 96 E	31a	BYM 56E, BYW 18/1000, BYW 96E
BYW 88-...(M)	Tho	Si-Di	P Rr, 50...1200V, 12A(Tc=125°), Uf<1,25V(35A)		32a	DO-4			BYX 75...81, BYX 99/..., 1N4506...11, ++
BYW 88-...R,RM		Si-Di	=BYW 88-...:		32b	DO-4			BYX 75...81R, BYX 99/...R
BYW 89	Mot	Si-Br	Br Rr, 1000V, 15A(Tc=55°), Uf<1,1V(55A)		70	(13x25²)			KBPC 15-10
BYW 90/....(R)	Mot	Si-Di	P Rr, 50...1000V, 24A(Tc=150°), Uf<1,18V(75,4A)		(17)	=TO-220			-
BYW 91/....	Mot	Si-Di	FRr, 50...1000V, 24A(Tc=125°), Uf<1,15V(24A),<200ns		(17)	=TO-220			-
BYW 92/....(U)	Phi,Sie,++	Si-Di	FRr, 50...200V, 23A(Tc=125°), Uf<1,3V(100A), <50ns		32a	DO-5			BYX 65/...
BYW 92/....R		Si-Di	=BYW 92/...:		32b	DO-5			BYX 65/...R
BYW 93/....(U)	Mot,Phi	Si-Di	FRr, 50...200V, 50A(Tc=115°), Uf<1,3V(200A), <60ns		32a	DO-5			BYW 07/..., BYW 78/..., BYW 94/...
BYW 94/....	Mot,Phi	Si-Di	FRr, 50...200V, 70A(Tc=111°), Uf<0,85V(70A), <60ns		32a	DO-5			BYW 07/..., BYW 08/...
BYW 95(A...C)	Gie,Phi	Si-Di	FRr,contr.av. 200...600V, 3/15A, Uf<1,5V(5A),<250ns A=200V, B=400V, C=600V		31a	SOD-64	BYW 95 C	31a	BYM 36A...E
BYW 96(D,E)	Gie,Phi	Si-Di	=BYW 95: 800...1000V, <300ns D=800V, E=1000V		31a	SOD-64	BYW 96 E	31a	BYM 36A...E
BYW 98/....	Tho	Si-Di	FRr, 50...200V, 3A, Uf<1,1V(9A), <50ns		31a	DO-27A	BYV 28/200	31a	BYV 28/..., EGP 30A...D, FE 3A...D
BYW 99-...	Tho	Si-Di	Dual,50...200V, 2x15A(Tc=115°), Uf<1,25V(38A),<50ns		23f	TO-3			-
BYW 99P-...		Si-Di	=BYW 99-...:		18e	TO-3P			BYV 72/..., MUR 3005PT...3060PT
BYW 99PI-...		Si-Di	=BYW 99P-...: Iso		18e	TO-3P Iso			BYV 52/...PI
BYW 100/...	Tho,	Si-Di	FRr, 50...200V, 1,5A, Uf<1,2V(4,5A), <35ns		31a	(4x1,7Ø)	BYV 27/200	31a	BYD 74A...G, BYV 27/..., EGP 20A...D
BYW 172 D...G	Aeg	Si-Di	FRr, 200...400V, 3A, Uf<1,1V(3A), <100ns D=200V, F=300V, G=400V		31a	SOD-64	BYV 28/200 (f. BYW 172D)	31a	BYT 56..., BYW 178
BYW 178	Aeg	Si-Di	FRr, 800V, 3/15A, Uf<1,9V(3A), <60ns		31a	SOD-64			BYT 56K...M
BYX									
BYX 10(G,GP)	Mot,Phi	Si-Di	Rr, 800/1600V, 0,36/3A, Uf<1,6V(2A) G: SOD-57, GP: DO-41		31a	DO-14	BY 133	31a	BY 231/1500, BY 269, EM 516, GP 10Y
BYX 11	Phi	Si-Di	Rr, 2000V, 0,01A, Uf<1V(0,1A)		31a	DO-14	BA 203/20	31a	BAY 91, BY 203/20, SHG 2...2,5

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BYX 13/....	Phi	Si-Di	P Rr, 400…1600V, 20/100A, Uf<0,9V(1A)		73a	SOD-5			-
BYX 13/....R		Si-Di	=BYX 13/...:		73b	SOD-5			D21S/..., D24/...
BYX 14/....	Phi	Si-Di	P Rr, 400…1200V, 150A(Tc=100°), Uf<1,8V(750A)		74a				-
BYX 14/....R		Si-Di	=BYX 14/...:		74b				-
BYX 15	Phi	Si-Di	P Rr, 1200V, 40A(Tc=125°), Uf<0,9V(1A)		73a	DO-30			-
BYX 16	Phi	Si-Di	=BYX 15:		73b	DO-30			D30S/..., D34/...
BYX 20/200	Phi	Si-Di	P Rr, 200V, 25A(Tc=142°), Uf<1,2V(25A)		75a	DO-21			1N3493…3495
BYX 20/200R		Si-Di	=BYX 20/200:		75b	DO-21			DS 25-02A…06A, 1N3493R…3495R
BYX 21(L)/....	Phi	Si-Di	P Rr, 50…200V, 25A(Tc=100°), Uf<1,6V(80A)		75a	DO-21			1N3491…3495
BYX 21(L)/....R		Si-Di	=BYX 21(L)/...:		75b	DO-21			DS 25-01A…06A, 1N3491R…3495R
BYX 22/....	Phi	Si-Di	Rr, 200…1200V, 1,4/15A, Uf<1,5V(5A)		34a	DO-1			BY 226…227, GP 15D…M, 1N5393…99, ++
BYX 23/....	Phi	Si-Di	P Rr, contr.av., 400…1000V, 100A, Uf<1,6V(500A)		73a	DO-30			(1N3291…32979)
BYX 24	Phi	Si-Di	Dual Rr, 800V, 0,8A		42(AAKK)	(7x10x5)			-
BYX 25/....	Phi	Si-Di	P Rr, 600…1400, 20A(Tc=125°), Uf<1,8V(50A)		32a	DO-4			-
BYX 25/....R		Si-Di	=BYX 25/...:		32b	DO-4			DS 17-07A…16A, SSi E2040…E20100
BYX 26/....	Phi	Si-Di	Rr, 60…150V, 0,25A, Uf<0,9V(0,25A)		31a				BA 157…159, BY 401…405, 1N4001…07, ++
BYX 27/....	Phi	Si-Di	P Rr, contr.av., 400…1000V, 250A(Tc=125°)		74a				-
BYX 28/....	Phi	Si-Di	P Rr, 200…400V, 25A(Tc=100°), Uf<1,45V(80A)		75a	DO-21			1N3493…3495
BYX 28/....R		Si-Di	=BYX 28/...:		75b	DO-21			DS 25-02A…06A, 1N3493R…3495R
BYX 29/....	Phi	Si-Di	kV-Rr P, contr.av., 75…150kV, 0,05A(Tc=100°)						-
BYX 30/....	Phi	Si-Di	P Rr, contr.av., 200…600V, 14A(Tc=100°), <350ns		32a	DO-4			BYX 46/...
BYX 30/....R		Si-Di	=BYX 30/...:		32b	DO-4			BYX 46/...R
BYX 32/....	Phi	Si-Di	P Rr, 200…1600V, 100A(Tc=100°), Uf<1,7V(500A)		73a	DO-30			1N3289…3297
BYX 32/....R		Si-Di	=BYX 32/...:		73b	DO-30			DS 80-…A, 1N3289R…3297R
BYX 33/....(R)	Phi	Si-Di	P Rr, 200…1600V, 250A(Tc=100°), Uf<1,8V(1250A)		74a,b				-
BYX 34/....	Phi	Si-Di	P Rr, contr.av., 200…500V, 60A(Tc=100°), <600ns		73a	SOD-5			BYT 60/...
BYX 34/....R		Si-Di	=BYX 34/...:		73b	SOD-5			BYT 60/...R
BYX 35	Phi	Si-Di	kV-Rr, 31,5/37kV, 0,05/0,16A, Uf<25V(10mA)		31a	(70x15Ø)			-
BYX 36/....	Phi	Si-Di	Rr, 150…600V, 1/5A, Uf<1,2V(1A)		31a	DO-15	BYD 33 M	31a	BYW 27/..., BYX 55/..., 1N4003…4007, ++
BYX 37		Si							
BYX 38/....	Mot,Phi	Si-Di	P Rr, 300…1200V, 6A(Tc=110°), Uf<1,7V(20A)		32a	DO-4			BYX 39/...
BYX 38/....R		Si-Di	=BYX 38/...:		32b	DO-4			BYX 39/...R
BYX 39/....	Phi	Si-Di	P Rr, contr.av., 600…1400V, 6A(Tc=125°), Uf<1,7V		32a	DO-4			-
BYX 39/....R		Si-Di	=BYX 39/...:		32b	DO-4			-
BYX 40/....	Phi	Si-Di	P Rr, contr.av., 600…1000V, 12A(Tc=125°), Uf<2,5V		32a	DO-4			1N4508…4511
BYX 40/....R		Si-Di	=BYX 40/...:		32b	DO-4			-
BYX 42/....	Phi	Si-Di	P Rr, 300…1200V, 10A(Tc=125°), Uf<1,4V(15A)		32a	DO-4			BYW 88/..., BYX 98/..., BYX 99/..., ++
BYX 42/....R		Si-Di	=BYX 42/...:		32b	DO-4			BYW 88/...R, BYX 98/...R, BYX 99/...R, ++
BYX 42/....T	Tsm	Si-Di	=BYX 42/...:		32b	DO-4			BYW 88/...R, BYX 98/...R, BYX 99/...R, ++
BYX 45/....R	Phi	Si-Di	Rr, contr.av., 200…1400V, 1,5/15A, Uf<1,45V(5A)		34b	DO-1			BYW 52…56, SSiB9860A…9890A
BYX 46/....	Phi	Si-Di	P Rr, contr.av., 200…600V, 15A(125°), <200ns		32a	DO-4			BYX 30/...
BYX 46/....R		Si-Di	=BYX 30/...:		32b	DO-4			BYX 30/...R
BYX 47	Phi	Si-Di	Rr, 2000V, 6A, Uf<2V(0,05A)		31a	DO-7			-
BYX 48/....	Phi	Si-Di	P Rr, 300…1200V, 6A(Tc=125°), Uf<1,8V(15A)		32a	DO-4			BYX 38/..., BYX 39/..., BYX 42/..., ++
BYX 48/....R		Si-Di	=BYX 48/...:		32b	DO-4			BYX 38/...R, BYX 39/...R, BYX 42/...R, ++
BYX 49/....	Phi	Si-Di	P Rr, 300…1200V, 6A(Tc=85°), Uf<2,3V(20A)		26h	SOD-38			-
BYX 49/....R		Si-Di	=BYX 49/...:		26j	SOD-38			-
BYX 50/....	Mot,Phi	Si-Di	FRr, contr.av., 200…600V, 7A(Tc=103°), <500ns		32a	DO-4			-
BYX 50/....R		Si-Di	=BYX 50/...:		32b	DO-4			-
BYX 51/....(R)	Phi	Si-Di	P Rr, 1200…2000V, 400A(Tc=115°), Uf<1,5V(1250A)		74a,ab				-
BYX 52/....	Phi	Si-Di	P Rr, 300…1200V, 40A(Tc=125°), Uf<1,8V(150A)		32a	DO-5			BYX 56..., BYX 97/...
BYX 52/....R		Si-Di	=BYX 52/...:		32b	DO-5			BYX 56…R, BYX 97/...R
BYX 53	Ssc	Si-Di	Rr, 2000V, 0,05A, Uf<6,5V(0,05A)		31a	DO-7	BY 203/20	31a	BY 203/20, SHG 2…2,5, 1N5181
BYX 54	Ssc	Si-Di	=BYX 53: 3000V		31a	DO-7			1N5181
BYX 55/....(GP,P)	Mot,Phi,Gie	Si-Di	FRr, 350…600V, 1,2/8A, Uf<1,25V(5A), <750ns BYX 55/...GP,P[Gie]: DO-27A		31a	SOD-18	BYD 33 M	31a	BY 231/..., RGP 15G…M, MR 814…818, ++
BYX 56/....	Phi	Si-Di	P Rr, contr.av., 600…1400V, 40A(Tc=125°), Uf<1,8V		32a	DO-5			-
BYX 56/....R		Si-Di	=BYX 56/...:		32b	DO-5			-
BYX 57/....	Tho	Si-Di	Rr, contr.av., 500…600V, 0,4A, Uf<1V(0,4A),<200ns		31a	DO-7	BYW 95 C	31a	BYT 11/..., BYV 26C…E, BYV 95C
BYX 58/....	Tho	Si-Di	FRr, 50…400V, 1/4A, Uf<1,3V(1A), <250ns		34a	DO-13	BYD 33 M	31a	BYV 12…16, BYX 92/..., RGP 10A…M, ++
BYX 59/....	Phi	Si-Di	P Rr, 200…500V, 40A, Uf<1,8V(250A), <600ns		73a	SOD-5			(BYX 56/..., BYX 97/...)
BYX 60/....	Tho	Si-Di	Rr, 50…1000V, 0,4/1A, Uf<1,2V(0,4A)		31a	DO-7	BA 159	31a	BA 157…159, BYW 27/..., 1N4001…07, ++
BYX 61/....(M)	Mot,Tho	Si-Di	P Rr, 50…400V, 12A(Tc=100°), Uf<1,4V(12A), <100ns		32a	DO-4			BYT 12/..., BYT 61/..., BYV 30/...
BYX 61/....R,RM		Si-Di	=BYX 61/...:		32b	DO-4			BYT 12/...R, BYT 61/..., BYV 30/...R
BYX 62/....(M)	Tho	Si-Di	P Rr, 600…800V, 12A(Tc=100°), Uf<1,4V(12A),<200ns		32a	DO-4			BYT 12/..., BYT 61/..., BYV 30/...
BYX 62/....R,RM		Si-Di	=BYX 62/...:		32b	DO-4			BYT 12/...R, BYT 61/...R, BYV 30/...
BYX 63/600(M)	Tho	Si-Di	P Rr, 600V, 20(Tc=100), Uf<1,4V(20A), <200ns		32a	DO-5			BYT 65/..., BYX 64/...
BYX 63/600R,RM		Si-Di	=BYX 63/600(M):		32b	DO-5			BYT 65/...R, BYX 64/...R
BYX 64/600(M)	Tho	Si-Di	P Rr, 600V, 30A(Tc=100°), Uf<1,4V(30A), <200ns		32a	DO-5			BYT 65/..., MR 866
BYX 64/600R,RM		Si-Di	=BYX 64/...:		32b	DO-5			BYT 65/...R, MR 866R
BYX 65/....(M)	Mot,Tho	Si-Di	P Rr, 50…400V, 30A(Tc=100°), Uf<1,5V(30A), <100ns		32a	DO-5			BYT 30/..., BYV 92/...
BYX 65/....R,RM		Si-Di	=BYX 65/...:		32b	DO-5			BYT 30/...R, BYV 92/...R
BYX 66/....(M)	Mot,Tho	Si-Di	P Rr,400…1000V, 12A(Tc=100°), Uf<1,5V(12A),<500ns		32a	DO-4			BYT 61/...
BYX 66/....R,RM		Si-Di	=BYX 66/...:		32b	DO-4			BYT 61/...R
BYX 67/....	Tho	Si-Di	P Rr,400…1000V, 30A(Tc=100°), Uf<1,5V(30A),<500ns		32a	DO-5			BYT 65/...
BYX 67/....R		Si-Di	=BYX 67/...:		32b	DO-5			BYT 65/...R
BYX 68	Fer	Si-Di	Rr, 1000V, 1A, Uf<1,2V(1A)		34a	DO-1	BY 133	31a	BY 127, BY 133, BY 227, 1N4007, ++
BYX 69	Fer	Si-Di	=BYX 68:		31a	DO-41	BY 133	31a	BY 127, BY 133, BY 227, 1N4007, ++
BYX 70/....	Phi	Si-Di	FRr, 100…600V, 1/5A, Uf<1,2V(1A), <200ns		31a	SOD-22	BYD 33 M	31a	BY201/..., BYT11/..., BYX92/..., RGP10B…M
BYX 71/....	Phi	Si-Di	TV Rr, 350…600V, 7A(Tc=85°), Uf<1,25V(5A), <450ns		26h	SOD-38	(BY 329/1200)[4]	17k	BYW 19/..., (BY 229/...)[4]
BYX 71/....R		Si-Di	=BYX 71/...:		26j	SOD-38	(BY 329/1200)[4]	17k	BY 277/...R, BYW 19/...R, (BY 229/...R)[4]
BYX 72/....	Phi	Si-Di	P Rr, 150…500V, 10A(Tc=75°), Uf<1,25V(20A)		26h	SOD-38			(BY 239/...)[4]
BYX 72/....R		Si-Di	=BYX 72/...:		26j	SOD-38			(BY 239/...R)[4]
BYX 73(A,B)	Tho	Si-Di	Schottky, 20(A=40, B=60)V, 5A(Tc=100°), Uf<0,7(5A)		32a	DO-4			BYS 15, BYV 120/..., MBR 1520…1540
BYX 74/....	Aei	Si-Br	Br Rr, 100…800V, 1,5A		33(+≈≈-)	(17x12x6)	B250C1500	33	B80C1500…B600C1500, etc.
BYX 75	Mot	Si-Di	P Rr, 50/60V, 12A(Tc=145°), Uf<0,95V(12A)		32a	DO-4			BYW 88/50, BYX 99/300, 1N4506…4511
BYX 75 R		Si-Di	=BYX 75:		32b	DO-4			BYW 88/50R, BYX 99/300R
BYX 76	Mot	Si-Di	=BYX 75: 100/120V		32a	DO-4			BYW 88/100, BYX 99/300, 1N4506…4511
BYX 76 R		Si-Di	=BYX 76:		32b	DO-4			BYW 88/100R, BYX 99/300R
BYX 77	Mot	Si-Di	=BYX 75: 200/240V		32a	DO-4			BYW 88/200, BYX 99/300, 1N4506…4511
BYX 77 R		Si-Di	=BYX 77:		32b	DO-4			BYW 88/200R, BYX 99/300R
BYX 78	Mot	Si-Di	=BYX 75: 400/480V		32a	DO-4			BYW 88/400, BYX 99/600, 1N4507…4511
BYX 78 R		Si-Di	=BYX 78:		32b	DO-4			BYW 88/400R, BYX 99/600R

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BYX 79	Mot	Si-Di	=BYX 75: 600/720V		32a	DO-4			BYW 88/600, BYX 99/600, 1N4508…4511
BYX 79 R		Si-Di	=BYX 79:		32b	DO-4			BYW 88/600R, BYX 99/600R
BYX 80	Mot	Si-Di	=BYX 75: 800/1000V		32a	DO-4			BYW 88/800, BYX 99/900, 1N4509…4511
BYX 80 R		Si-Di	=BYX 80:		32b	DO-4			BYW 88/800R, BYX 99/900R
BYX 81	Mot	Si-Di	=BYX 75: 1000/1200V		32a	DO-4			BYW 88/1000, BYX 99/1200, 1N4510…4511
BYX 81 R		Si-Di	=BYX 81:		32b	DO-4			BYW 88/1000R, BYX 99/1200R
BYX 82	Aeg,Gie	Si-Di	Rr, 200V, 1,5/10A, Uf<1V(1A), <4µs		31a	SOD-57	BYD 33 M	31a	BY 226…227, (R)GP 15D…M, 1N5393…99,++
BYX 83	Aeg,Gie	Si-Di	=BYX 82: 400V		31a	SOD-57	BYD 33 M	31a	BY 226…227, (R)GP 15G…M, 1N5395…99,++
BYX 84	Aeg,Gie	Si-Di	=BYX 82: 600V		31a	SOD-57	BYD 33 M	31a	BY 226…227, (R)GP 15J…M, 1N5397…99,++
BYX 85	Aeg,Gie	Si-Di	=BYX 82: 800V		31a	SOD-57	BYD 33 M	31a	BY 227, (R)GP 15K…M, 1N5398…5399, ++
BYX 86	Aeg,Gie	Si-Di	=BYX 82: 1000V		31a	SOD-57	BYD 33 M	31a	BY 227, BY 350/1300, (R)GP 15M, 1N5399
BYX 87	Aeg,Gie	Si-Di	=BYX 82: 1200V		31a	SOD-57	BY 255	31a	BY 227, BY 255, BY 350/1300
BYX 88	Tho	Si-Di	Schottky, 20V, 30A(Tc=25°), Uf<1V(100A)		75a	DO-21			-
BYX 89(A,B)	Tho	Si-Di	Schottky,20(A=40, B=60)V, 50A(Tc=25°),Uf<0,65(50A)		32a	DO-5			BYS 50…51, BYS 60/…, BYV 23/…
BYX 90	Phi	Si-Di	kV-Rr, 6/7,5kV, 0,2/3A, Uf<15V(2A)		31a	SOD-18			-
BYX 90 G		Si-Di	=BYX 90: 0,55A, Uf<14,5V(2A), <350ns		31a	SOD-64			-
BYX 91/….	Phi	Si-Di	kV-Rr, 115…225kV, 0,2A(Tc=50°),						-
BYX 92/….	Tho	Si-Di	FRr, 50…400V, 1/4A, Uf<1,3V(1A), <100ns		34a	DO-13	BYV 27/200	31a	BYT 11/…, BYV 36A…E, FE 1A…D
BYX 93	Fer	Si-Di	Schottky, 200V, 60A, Uf<2V(100A)		32a	DO-5			-
BYX 93 R		Si-Di	=BYX 93:		32b	DO-5			-
BYX 94	Phi	Si-Di	Rr, 1250V, 1/10A, Uf<1,5V(5A)		31a	DO-15	BY 133	31a	BY 133, BY 255, EM 513, GP 10V…Y
BYX 95	Phi	Si-Di	Rr, 1300V, 1/10A, Uf<1,3V(2A)		31a	DO-15	BY 133	31a	BY 133, BY 255, EM 513, GP 10V…Y
BYX 96/….(U)	Phi	Si-Di	P Rr, 300…1600V, 30A(Tc=125°), Uf<1,7V(100A)		32a	DO-4			-
BYX 96/….R		Si-Di	=BYX 96/…:		32b	DO-4			-
BYX 97/….	Phi	Si-Di	P Rr, 300…1600V, 40A(Tc=125°), Uf<1,45V(150A)		32a	DO-5			BYX 56/…
BYX 97/….R		Si-Di	=BYX 97/…:		32b	DO-5			BYX 56/…R
BYX 98/….	Mot,Phi	Si-Di	P Rr, 300…1200V, 10A(Tc=97°), Uf<1,7V(20A)		32a	DO-4			BYW 88/…, BYX 42/…, 1N4606…4611
BYX 98/….R		Si-Di	=BYX 98/…:		32b	DO-4			BYW 88/…R, BYX 42/…R
BYX 99/….	Mot,Phi	Si-Di	P Rr, 300…1200V, 15A(Tc=129°), Uf<1,55V(50A)		32a	DO-4			BYX 25/…, BYX 96/…
BYX 99/….R		Si-Di	=BYX 99/…:		32b	DO-4			BYX 25/…R, BYX 96/…R
BYX 110 GP	Phi	Si-Di	kV-Rr, contr.av., …400Hz, 8/9kV, 0,35A, Uf<8,5V		31a	(21x9mmØ)			-
BYX 120 G	Phi	Si-Di	kV-Rr, Kfz-Zündg./Ignition, 3kV, 0,1/5A, Uf<4,4V		31a	=SOD-61			-
BYY									
BYY 10	Phi	Si-Di	Rr, 800V, 0,5/5A(Tc=100°), Uf<1,45V(5A)			(6x11mmØ)			(BY 127, BY 133, BY 227, 1N4006…07,++)[4]
BYY 15	Phi	Si-Di	P Rr, 400/800V, 36A(Tc=100°), Uf<1,8V(200A)		73a	DO-30			-
BYY 16	Phi	Si-Di	=BYY 15:		73b	DO-30			D30S/…
BYY 19	Itt	Si-Di	P Rr, 1000/1500V, 4A(Tc=25°)		32a	DO-4			(BY 359/1500)[4]
BYY 20(200)	Phi	Si-Di	P Rr, 75/200V, 18A(Tc=25°), Uf<1,2V(12A)		75a	DO-21			1N3493…3495
BYY 21(200)	Phi	Si-Di	=BYY 20:		75b	DO-21			DS25-02A…06A, 1N3493R…3495R
BYY 22	Phi	Si-Di	P Rr, 200/400V, 12/50A, Uf<1,5V(50A)		73a	SOD-5			-
BYY 23	Phi	Si-Di	=BYY 22:		73b	SOD-5			D24/400B…1800B, D21S/1000…1400
BYY 24	Phi	Si-Di	=BYY 22: 400/800V		73a	SOD-5			-
BYY 25	Phi	Si-Di	=BYY 24:		73b	SOD-5			D24/800B…1800B, D21S/1000…1400
BYY 27	Phi	Si-Di	P Rr, 150/300V, 220A(Tc=175°), Uf<1V(220A)		73a	TO-108			1N3737…3744
BYY 28	Phi	Si-Di	=BYY 27: 250/500V		73a	TO-108			1N3739…3744
BYY 29	Phi	Si-Di	=BYY 27: 325/650V		73a	TO-108			1N3740…3744
BYY 30	Phi	Si-Di	=BYY 27: 400/800V		73a	TO-108			1N3741…3744
BYY 31	Itt	Si-Di	Rr, 150V, 1/10A, Uf<1,3V(2A)		34a	DO-13	BY 133	31a	BY 126, BY 135, BY 226, 1N4003…07, ++
BYY 32	Itt	Si-Di	=BYY 31: 300V		34a	DO-13	BY 133	31a	BY 126, BY 134, BY 226, 1N4004…07, ++
BYY 33	Itt	Si-Di	=BYY 31: 450V		34a	DO-13	BY 133	31a	BY 126, BY 134, BY 226, 1N4005…07, ++
BYY 34	Itt	Si-Di	=BYY 31: 600V		34a	DO-13	BY 133	31a	BY 126, BY 134, BY 226, 1N4005…07, ++
BYY 35	Itt	Si-Di	=BYY 31: 750V		34a	DO-13	BY 133	31a	BY 127, BY 133, BY 227, 1N4006…07, ++
BYY 36	Itt	Si-Di	=BYY 31: 900V		34a	DO-13	BY 133	31a	BY 127, BY 133, BY 227, 1N4007, ++
BYY 37	Itt	Si-Di	=BYY 31: 1050V		34a	DO-13	BY 133	31a	BY 127, BY 133, BY 227, 1N4007, ++
BYY 38	Phi	Si-Di	=BYY 27: 500/1000V		73a	TO-108			1N3742…3744
BYY 39	Phi	Si-Di	=BYY 27: 600/1200V		73a	TO-108			1N3743…3744
BYY 39/….	Phi	Si-Di	P Rr, 200…2400V, 220A(Tc=135°), Uf<1,4V(600A)		73a	TO-108			1N3736…3744
BYY 39/….R		Si-Di	=BYY 39/…:		73b	TO-108			1N3736R…3744R
BYY 56	Aeg	Si-Di	Rr, 1200V, 0,56/5A, Uf<1,2V(1A)		12a	(11x11x6)	SKE 4F2/10	33a	BY 208/1000, BY 245/1200, (R)GP 10M, ++
BYY 57/….	Aeg	Si-Di	P Rr, 75…700V, 35A(Tc=142°), Uf<0,9V(10A)		75b	DO-21			SSi E1205…1240, 1N3660R…3665R
BYY 58/….	Aeg	Si-Di	=BYY 57/…:		75a	DO-21			SSi E1105…1140, 1N3660…3665
BYY 59	Aeg	Si-Di	Rr, 200/300V, 1,2/10A, Uf<1,1V(2,8A)		12a	(11x11x6)	BY 133	31a	BY 226, (R)GP 15G…M, 1N5394…5399, ++
BYY 60	Aeg	Si-Di	=BYY 59: 400/600V		12a	(11x11x6)	BY 133	31a	BY 226, (R)GP 15J…M, 1N5397…5399, ++
BYY 61	Aeg	Si-Di	=BYY 59: 600/900V		12a	(11x11x6)	BY 133	31a	BY 227, BY 350/1300, (R)GP 15M, 1N5399
BYY 62	Aeg	Si-Di	=BYY 59: 800/1200V		12a	(11x11x6)			BY 227, BY 350/1300, GH 3E…F
BYY 67	Phi	Si-Di	P Rr, 300/600V, 10A(Tc=125°), Uf<0,8V(10A)		73a	SOD-5			-
BYY 68	Phi	Si-Di	=BYY 67:		73b	SOD-5			D24/800B…1800B, D21S/1000…1400
BYY 69	Phi	Si-Di	=BYY 67: 500/1000V		73a	SOD-5			-
BYY 70	Phi	Si-Di	=BYY 69:		73b	SOD-5			D24/1200B…1800B, D21S/1000…1400
BYY 71	Phi	Si-Di	=BYY 67: 600/1200V		73a	SOD-5			-
BYY 72	Phi	Si-Di	=BYY 71:		73b	SOD-5			D24/1200B…1800B, D21S/1000…1400
BYY 73	Phi	Si-Di	P Rr, 300/600V, 40A(Tc=150°), Uf<1V(40A)		73a	DO-30			-
BYY 74	Phi	Si-Di	=BYY 73:		73b	DO-30			D60/800…1400, DS42-07A…16A
BYY 75	Phi	Si-Di	=BYY 73: 500/1000V		73a	DO-30			-
BYY 76	Phi	Si-Di	=BYY 75:		73b	DO-30			D60/1200…1400, DS42-11A…16A
BYY 77	Phi	Si-Di	=BYY 15: 600/1200V		73a	DO-30			-
BYY 78	Phi	Si-Di	=BYY 77:		73b	DO-30			D30S/1200…1400, D34/1200B…1800B
BYY 88	Itt	Si-Di	P Rr, 150V, 1A(Ta=50°), 4A(Tc=25°), Uf<1,3V(2A)		32a				BYX 38/300…1200, (BY 205/200…1000)[4]
BYY 89	Itt	Si-Di	=BYY 88: 300V		32a				BYX 38/300…1200, (BY 205/400…1000)[4]
BYY 90	Itt	Si-Di	=BYY 88: 600V		32a				BYX 38/600…1200, (BY 205/600…1000)[4]
BYY 91	Itt	Si-Di	=BYY 88: 1200V		32a				BYX 38/1200, (BY 359/1300)[4]
BYY 92	Itt	Si-Di	=BYY 88: 1600V		32a				(BY 359/1500)[4]
BYY 93	Phi	Si-Di	P Rr, 400/800V, 150A(Tc=130°)		32a	DO-4			-
BYY 94	Phi	Si-Di	=BYY 93:		32b	DO-4			-
BYY 95	Phi	Si-Di	=BYY 93: 600/1200V		32a	DO-4			-
BYY 96	Phi	Si-Di	=BYY 95:		32b	DO-4			-
BYZ									
BYZ 10	Phi	Si-Di	P Rr, 800/1200V, 6/20A, Uf<1,7V(5A)		32a	DO-4	BY 329/1200[4]	17k	BYX 38/1200, (BY 359/1300)[4]
BYZ 11	Phi	Si-Di	=BYZ 10: 600/900V		32a	DO-4	BY 329/1200[4]	17k	BYX 38/900…1200V, (BY 359/1000,++)[4]
BYZ 12	Phi	Si-Di	=BYZ 10: 400/600V		32a	DO-4	BY 329/1200[4]	17k	BYX 38/600…1200, (BY 205/600…1000,++)[4]
BYZ 13	Phi	Si-Di	=BYZ 10: 200/300V		32a	DO-4	BY 329/1200[4]	17k	BYX 38/300…1200, (BY 205/400…1000,++)[4]

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BYZ 14	Phi	Si-Di	=BYY 15: 200/400V		73a	DO-30			-
BYZ 15	Phi	Si-Di	=BYZ 14:		73b	DO-30			D30S/1000…1400, D34/400B…1800B
BYZ 16	Phi	Si-Di	=BYZ 10:		32b	DO-4	BY 329/1200[4]	17k	BYX 38/1200R, (BY 359/1300)[4]
BYZ 17	Phi	Si-Di	=BYZ 11:		32b	DO-4	BY 329/1200[4]	17k	BYX 38/900R…1200R, (BY 359/1000,++)[4]
BYZ 18	Phi	Si-Di	=BYZ 12:		32b	DO-4	BY 329/1200[4]	17k	BYX 38/600R…1200R,(BY 205/600…1000,++)[4]
BYZ 19	Phi	Si-Di	=BYZ 13:		32b	DO-4	BY 329/1200[4]	17k	BYX 38/300R…1200R,(BY 205/400…1000,++)[4]
BZ									
BZ		Si-P	=BCX 71RL (SMD-Marking)		35	SOT-23			›BCX 71RL
BZ-050….-350	Njr	Z-Di	5…35V, 5%, 1W		31a	DO-41	Z-Diode ….V	31a	BZW22/…, BZX61/…, ZPY…, 1N4733…53,++
BZ 100	Phi	Z-Di	3,9V, 10%, 0,3W		31a	DO-7	Z-Diode 3,9V	31a	BZX55/C3V9, BZX79/C3V9, ZPD3,9, 1N4730++
BZ 102/0V7….3V4	Aeg	Si-St	0,7…3,4V(5mA), 0,25…0,05A, 0,25W		31a	DO-7	Z-Diode ….V	31a	BZX 75/…
BZD….BZT									
BZD 10/C3V3….200	Sie	Z-Di	3,3…200V, 5%, 1,3W		34a	DO-13	Z-Diode ….V		BZW22/…, BZX61/…, ZPY…, 1N5313…56,++
BZD 23/C3V9….270	Phi	Z-Di	Z, TAZ, 3,9…270V, 5%, 2,5W, Pbr=300W(0,1ms)		31a	SOD-81			BZW 04/…
BZD 27/C3V6… 270	Phi	Z-Di	SMD, Z, TAZ, 3,9…270V, 5%, 2,3W, Pbr=300W(0,1ms)		72a(3,4mm)	SOD-80	Z-Di …V(SMD)	72a(3,4mm)	BZT 55/C…, HZK …, RLZ 5221B…
BZG 03-10…-270	Phi	Z-Di	=BZD 27/10…270: 1,25W, Pbr=600W(100µs)		71a(5mm)				BZG 04/…, HZF …, MA 1Z…
BZG 04/8V2…430	Aeg	Z-Di	TAZ, 8,2…430V, 5%, 1,25W, Pbr=300W(10/1000µs)		71a(5mm)				-
BZG 05/3V3…15	Aeg	Z-Di	Z, 3,3…15V, 5%, 1,25W, Pbr=60W(100µs)		71a(5mm)				BZG 03/…, PTZ…, RD…FM
BZM 85/C2V7…200	Tho	Z-Di	=BZX 85/C…: SMD		72a(5mm)	MELF			-
BZT 03/C,D6V2…270	Aeg,Phi	Z-Di	Z,TAZ, 6,2…270V, C=5,D=10%, 1,3W, Pbr=600W(100µs)		31a	SOD-57			BZW 04/…, BZW 06/…
BZT 88/C2,4…75	Phi	Z-Di	=BZX 55/C…: 0,5W		72a(3,5mm)	DO-213			BZD 27/C…
BZV									
BZV 10	Phi	Ref-Di	6,5V, 5%, 50mA, 0,4W, ±0,01%/°C, <50Ω		31a	DO-35			BZV 27, BZX 90, 1N4575, 1N4580,++
BZV 11	Phi	Ref-Di	=BZV 10: ±0,005%/°C		31a	DO-35			BZV 28, BZX 91, 1N4576, 1N4581,++
BZV 12	Phi	Ref-Di	=BZV 10: ±0,002%/°C		31a	DO-35			BZV 29, BZX 92, 1N4577, 1N4582,++
BZV 13	Phi	Ref-Di	=BZV 10: ±0,001%/°C		31a	DO-35			BZV 30, BZX 93, 1N4578, 1N4583,++
BZV 14	Phi	Ref-Di	=BZV 10: ±0,0005%/°C		31a	DO-35			BZV 31, BZX 94, 1N4579, 1N4584,++
BZV 15/C7V5….75	Phi	Z-Di	7,5…75V, 5%, 15W(Tc=82°), 2,2W(Ta=25°)		26h	SOD-38			-
BZV 15/C7V5R…75R		Z-Di	=BZV 15/C…:		26j	SOD-38			-
BZV 16/C3V3….100	Tho	Z-Di	3,3…100V, 5%, 3W		34a	DO-13			BZT03/…, BZV40/…, BZV48/…, 1N5333…78
BZV 17/C5V6….56	Tho	Z-Di	5,6…56V, 5%, 0,25W, In		31a	DO-7	(Z-Diode ….V)	31a	BZV39/…, 1N4099…4127
BZV 18/C5V6….12	Tho	Z-Di	5,6…12V, 5%, 1W		31a	DO-29	Z-Diode ….V	31a	BZW22/…, BZX61/…, ZPY…, 1N4734…42,++
BZV 19M/C4V7….47	Fer	Z-Di	4,7…47V, 5%, 0,4W		40d	=TO-92	Z-Diode ….V	31a	BZX55/…, BZX79/…, ZPD…, 1N5728…52,++
BZV 19N/C4V7….47		Z-Di	=BZV 19M/…:		31a	DO-35	Z-Diode ….V	31a	›BZV 19M/…
BZV 19P/C4V7….47		Z-Di	=BZV 19M/…:		31a	DO-7	Z-Diode ….V	31a	›BZV 19M/…
BZV 20	Tho	Z-Di	120…280V		12				-
BZV 21 A	Phi	Ref-Di	8,5V, 7,5mA, 0,4W, ±0,001%/°C, <20Ω		31a	(19x7mmØ)			1N3157, 1N4778, 1N4783
BZV 21 B		Ref-Di	=BZV 21A: ±0,002%/°C		31a	(19x7mmØ)			1N3156, 1N4777, 1N4782
BZV 21 C		Ref-Di	=BZV 21A: ±0,005%/°C		31a	(19x7mmØ)			1N3155, 1N4776, 1N4781
BZV 21 D		Ref-Di	=BZV 21A: ±0,01%/°C		31a	(19x7mmØ)			1N3154, 1N4775, 1N4780
BZV 22(A….D)	Phi	Ref-Di	=BZV 21(A…D): 12,5V, <30Ω		31a	(19x7mmØ)			1N4907…04, 1N4911…08, 1N4915…12,++
BZV 23(A….D)	Phi	Ref-Di	=BZV 21(A…D): 18,5V, <45Ω		31a	(19x7mmØ)			-
BZV 24(A….D)	Phi	Ref-Di	=BZV 21(A…D): 8,7V, 2mA, <60Ω		31a	(19x7mmØ)			›BZV 21(A…D)
BZV 25(A….D)	Phi	Ref-Di	=BZV 21(A…D): 13V, 2mA, <100Ω		31a	(19x7mmØ)			-
BZV 26(A….D)	Phi	Ref-Di	=BZV 21(A…D): 19V, 2mA, <150Ω		31a	(19x7mmØ)			2N4924…22, 1N4928…25, 1N4932…29,++
BZV 27(A)	Tho	Ref-Di	6,2V, 7,5mA, 0,4W, ±0,01%/°C, <15Ω(A: <10Ω)		31a	DO-35			BZV 10, BZX 90, 1N4575, 1N4580,++
BZV 28(A)	Phi	Ref-Di	=BZV 27(A): ±0,005%/°C		31a	DO-35			BZV 11, BZX 91, 1N4576, 1N4581,++
BZV 29(A)	Phi	Ref-Di	=BZV 27(A): ±0,002%/°C		31a	DO-35			BZV 12, BZX 92, 1N4577, 2N4582,++
BZV 30(A)	Phi	Ref-Di	=BZV 27(A): ±0,001%/°C		31a	DO-35			BZV 13, BZX 93, 1N4578, 1N4583,++
BZV 31(A)	Phi	Ref-Di	=BZV 27(A): ±0,0005%/°C		31a	DO-35			BZV 14, BZX 94, 1N4579, 1N4584,++
BZV 32(A….B)	Tho	Ref-Di	9V, 7,5mA, 0,5W, ±0,01%/°C, <20Ω		31a	DO-35			1N935, 1N4765
BZV 33(A….B)	Tho	Ref-Di	=BZV 32(A…B): ±0,005%/°C		31a	DO-35			1N936, 1N4766, 1N4771
BZV 34(A….B)	Tho	Ref-Di	=BZV 32(A…B): ±0,002%/°C		31a	DO-35			1N937, 1N4767, 1N4772
BZV 35(A….B)	Tho	Ref-Di	=BZV 32(A…B): ±0,001%/°C		31a	DO-35			1N938, 1N4768, 1N4773
BZV 36(A….B)	Tho	Ref-Di	=BZV 32(A…B): ±0,0005%/°C		31a	DO-35			1N939, 1N4769, 1N4774
BZV 37	Phi,Tho	Ref-Di	Ref, sym, TAZ, 6,5V, 5%, 50mA, 0,4W, <20Ω		31a	DO-34			-
BZV 38	Phi,Sie	Ref-Di	6,4V, 5%, 50mA, <20mV/°C, <20Ω		31a	DO-35			BZV 10…14, BZX 90…94, 1N4565…84,++
BZV 39/C0V8	Sie,Tho	Si-St	In, 0,73…0,83V(5mA), 0,25A, 0,5W (=BZX 55/…)		31a	DO-35	(1N4148)	31a	(BZX 55/C0V8)
BZV 39/C2V4….75	Sie,Tho	Z-Di	In, 2,4…75V, 5%, 0,5W (=BZX 55/…)		31a	DO-35	(Z-Diode ….V)	31a	1N4099…4131
BZV 40/C3V3….200	Sie	Z-Di	3,3…200V, 5%, 5W		31a	(8,6x3,5Ø)			BZV 48/…, 2N5338B…5388B
BZV 41/C2V7….47	Fer	Z-Di	2,7…47V, 5%, 0,75W		40d	=TO-92	Z-Diode ….V	31a	BZV85/…, BZX61/…, ZPY…, 1N4728…56,++
BZV 42/C2V7….47	Fer	Z-Di	2,7…47V, 5%, 0,75W		40d	=TO-92	Z-Diode ….V	31a	BZV85/…, BZX61/…, ZPY…, 1N4728…56,++
BZV 43(A….C)	Tho	Ref-Di	6,2V, 5mA, 0,25W, 62mV/°C, <20Ω, A=1%, B=2%, C=5%		31a	DO-35			BZV 10…14, BZX 90…94, 1N4565…4584,++
BZV 44(A….C)	Tho	Ref-Di	=BZV 43(A…C): 31mV/°C		31a	DO-35			BZV 10…14, BZX 90…94, 1N4565…4584,++
BZV 45(A….C)	Tho	Ref-Di	=BZV 43(A…C): 12mV/°C		31a	DO-35			BZV 10…14, BZX 90…94, 1N4565…4584,++
BZV 46/C1V5	Phi	Si-St	1,35…1,55V(5mA), 0,25W, -3,65mV/°C, <20Ω		31a	DO-35	Z-Diode 1,4V	31a	BZ 102/1V4, BZX 75/C1V4, ZTE 1,5
BZV 46/C2V0	Phi	Si-St	2…2,3V(5mA), 0,25W, -5,6mV/°C, <30Ω		31a	DO-35	Z-Diode 2,1V	31a	BZ 102/2V1, BZX 75/C2V1, ZTE 2
BZV 47/C3V3….200	Tho	Z-Di	3,3…200V, 5%, 2W		31a	DO-15			BZD 23/…, BZT 03/…, ZY …
BZV 48/C3V3….200	Tho	Z-Di	3,3…200V, 5%, 5W		31a	DO-27A			BZV 40/…, 1N5333B…5388B
BZV 49/C0V8	Sie	Z-Di	SMD, 0,73…0,83V, 1W(Tc=25°)		39q	SOT-89			-
BZV 49/C2V4….75	Phi,Sie	Z-Di	SMD, 2,4…75V, 5%, 1W(Tc=25°)		39q, 39j	SOT-89			BZX 78/…, RD …P
BZV 53A….B	Tho	Ref-Di	SMD, 5,89…6,51V(7,5mA), <15Ω A: ±0,01%/°C, B= 0,005%/°C		35p	SOT-23			-
BZV 54A….B	Tho	Ref-Di	SMD, 6,08…6,72V(0,5mA), <200Ω A: ±0,01%/°C, B= 0,005%/°C		35p	SOT-23			-
BZV 55/…0V8…200	Phi,Tho	Z-Di	=BZX 55/…: SMD, BZV55/B=2%, /C=5%, /F=3%		72a(3,4mm)	SOD-80	Z-Di …V(SMD)	72a(3,4mm)	BZD 27/…, HZK…, RLZ 5221B…
BZV 58/3V3…200	Tho	Z-Di	3,3…200V, 5%, 1,43W		31a	(8,5x3,5)	Z-Diode ….V	31a	BZV 40/…, BZV 48/…, 1N5333B…5388B
BZV 60/C….	Phi	Z-Di	=BZV 49/C…: 0,5W		31a	DO-34	Z-Diode ….V	31a	BZW22/…, BZX55/…, ZPD…, 1N5221…67,++
BZV 80	Phi	Ref-Di	=BZV 53A: SMD		72a(3,4mm)	SOD-80			-
BZV 81	Phi	Ref-Di	=BZV 53B: SMD		72a(3,4mm)	SOD-80			-
BZV 85/C3V6….75	Phi	Z-Di	3,6…75V, 5%, 1W		31a	DO-41	Z-Diode ….V	31a	BZW22/…, BZX61…, ZPY…, 1N4729…61A,++
BZV 86/1V4…3V2	Phi	Si-St	1,4…3,2V(5mA), 0,33W		31a	(4,2x1,8)	Z-Diode ….V	31a	BZ 102/…, BZX 75/…
BZV 87/1V4…3V2	Phi	Si-St	SMD, 1,4…3,2V(5mA), 0,35W		72a(3,4mm)	SOD-80			-
BZV 90/C2V4…C75	Phi	Z-Di	=BZV 49/C…: 1,3W		≈39°f	SOT-223			-
BZW									
BZW 03/…7V5…270	Aeg,Phi	Z-Di	TAZ, 7,5…270V, Pbr=1kW(0,1ms), BZW03/C=5%, /D=10%		31a	SOD-64			BZW07/…, BZW70/…, BZX70/…, BZY93/…
BZW 04/5V5…376(P)	Tho	Z-Di	TAZ, 5,5…376V, 5%, 1,7W, Pbr=400W(1ms)		31a	DO-15			BZW 06/…, 1N6102…6137
BZW 04/…B		Z-Di	=BZW 04/…: bidirektional/back to back		31l	DO-15			BZW 06/…B, 1N6102…6137
BZW 06/5V8…376(P)	Tho	Z-Di	TAZ, 5,8…376V, 5%, 1,7W, Pbr=600W(1ms)		31a	DO-15			BZW70/…, BZX70/…, BZY93/…

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
BZW 06/...B		Z-Di	=BZW 06/...: bidirektional/back to back		31l DO-15			-
BZW 07/10....110	Tho	Z-Di	TAZ, 10...110V, Pbr=700W(1ms)		31a DO-15			BZW 70/..., BZX 70/..., BZY 93/...
BZW 07/10B...110B		Z-Di	=BZW 07/...: bidirektional/back to back		31l DO-15			-
BZW 10/12....15	Phi	Z-Di-Br	TAZ Br, 12...15V		33(+≈-) (19x10x5)			-
BZW 11/7V0....171	Tho	Z-Di	TAZ, 7,5...171V, Pbr=1kW(1ms)		31a DO-27A			1N5630...5663
BZW 11/7V0B...171B		Z-Di	=BZW 11/...: bidirektional/back to back		31a DO-27A			1N6036...6069, 1N6139...6172
BZW 12/11....390	Tho	Z-Di	TAZ, 11...390V, Pbr=420W(10ms)		32a DO-4			-
BZW 13/11....390	Tho	Z-Di	TAZ, 11...390V, Pbr=1,2kW(10ms)		32a DO-5			-
BZW 14	Phi	Z-Di	TAZ, 12V		31a SOD-64			-
BZW 20	Sie	Si-N+Di+R	Spg.-Regler/Voltage Control, 20V, Ueb=8,4...9,5V		35a SOT-23			-
BZW 22/C1	Sie	Si-St	0,65...0,75V(5mA), 1,3W		31a DO-41			ZPY 1, ZY 1
BZW 22/C2V7....200	Aeg,Sie	Z-Di	2,7...200V, 5%, 1,3W		31a DO-41	Z-Diode V	31a	BZX61/..., BZX85/..., BZY97/..., 2N5913...56
BZW 25/12....120	Tho	Z-Di	TAZ, 12...120V, Pbr=2,5kW(1ms)		17k TO-220			-
BZW 30/12....324	Tho	Z-Di	TAZ, 12...324V, Pbr=3kW(1ms)		31a DO-27			-
BZW 50/8V2....180	Tho	Z-Di	TAZ, 8,2...180V, 5W, Pbr=5kW(1ms)		31a (9x8mmØ)			-
BZW 50/8V2B...180B		Z-Di	=BZW 50/...: bidirektional/back to back		31a (9x8mmØ)			-
BZW 70/5V6....62	Phi	Z-Di	TAZ, 5,6...62V, Pbr=700W(1ms)		31a SOD-18			BZX 70/..., BZY 93/...
BZW 86/7V5....62	Phi	Z-Di	TAZ, 7,5...62V, Pbr=13kW(1ms)		73a DO-30			-
BZW 86/7V5R...62R		Z-Di	=BZW 86/...:		73b DO-30			-
BZW 91/5V6....62	Phi	Z-Di	TAZ, 5,6...62V, Pbr=9,5kW(1ms), (BZY 91/...)		32a DO-5			BZY 91/...
BZW 91/5V6R...62R		Z-Di	=BZW 91/...:		32b DO-5			BZY 91/...R
BZW 93/5V6....62	Phi	Z-Di	TAZ, 5,6...62V, Pbr=400W(1ms), (=BZY 93/...)		32a DO-4			BZY 93/...
BZW 93/5V6R...62R		Z-Di	=BZW 93/...:		32b DO-4			BZY 93/...R
BZW 95/5V6....62	Phi	Z-Di	TAZ, 5,6...62V, Pbr=400W(1ms)		34a DO-1			BZW 04/...
BZW 96/3V9....7V5		Z-Di	TAZ, 3,9...7,5V, Pbr=110W(1ms)		34a DO-1			BZW 04/...
BZW 100/20...24	Tho	Z-Di	TAZ, 20...24V, 5W, Pbr=1,8kW(15ms)		31a (9x8mmØ)			-
BZX								
BZX 10	Fch,Sgs	Z-Di	6,2V, 5%, 0,4W		31a DO-7	Z-Diode 6,2V	31a	BZX55/..., BZX79/..., ZPD..., 1N5234...57,++
BZX 11	Fch,Sgs	Z-Di	=BZX 10: 6,8V		31a DO-7	Z-Diode 6,8V	31a	›BZX 10
BZX 12	Fch,Sgs	Z-Di	=BZX 10: 7,5V		31a DO-7	Z-Diode 7,5V	31a	›BZX 10
BZX 13	Fch,Sgs	Z-Di	=BZX 10: 8,2V		31a DO-7	Z-Diode 8,2V	31a	›BZX 10
BZX 14	Fch,Sgs	Z-Di	=BZX 10: 9,1V		31a DO-7	Z-Diode 9,1V	31a	›BZX 10
BZX 15	Fch,Sgs	Z-Di	=BZX 10: 10V		31a DO-7	Z-Diode 10V	31a	›BZX 10
BZX 16	Fch,Sgs	Z-Di	=BZX 10: 11V		31a DO-7	Z-Diode 11V	31a	›BZX 10
BZX 17	Fch,Sgs	Z-Di	=BZX 10: 12V		31a DO-7	Z-Diode 12V	31a	›BZX 10
BZX 18	Fch,Sgs	Z-Di	=BZX 10: 13V		31a DO-7	Z-Diode 13V	31a	›BZX 10
BZX 19	Fch,Sgs	Z-Di	=BZX 10: 15V		31a DO-7	Z-Diode 15V	31a	›BZX 10
BZX 20	Fch,Sgs	Z-Di	=BZX 10: 16V		31a DO-7	Z-Diode 16V	31a	›BZX 10
BZX 21	Fch,Sgs	Z-Di	=BZX 10: 18V		31a DO-7	Z-Diode 18V	31a	›BZX 10
BZX 22	Fch,Sgs	Z-Di	=BZX 10: 20V		31a DO-7	Z-Diode 20V	31a	›BZX 10
BZX 23	Fch,Sgs	Z-Di	=BZX 10: 22V		31a DO-7	Z-Diode 22V	31a	›BZX 10
BZX 24	Fch,Sgs	Z-Di	=BZX 10: 24V		31a DO-7	Z-Diode 24V	31a	›BZX 10
BZX 25	Fch,Sgs	Z-Di	=BZX 10: 27V		31a DO-7	Z-Diode 27V	31a	›BZX 10
BZX 26	Fch,Sgs	Z-Di	=BZX 10: 30V		31a DO-7	Z-Diode 30V	31a	›BZX 10
BZX 27	Fch,Sgs	Z-Di	=BZX 10: 33V		31a DO-7	Z-Diode 33V	31a	›BZX 10
BZX 29/C3V3....100	Phi	Z-Di	3,3...100V, 5%, 1,5W		31a DO-14	Z-Diode V	31a	BZV47/..., BZY97/..., ZY..., 1N5913...49,++
BZX 30/C3V3....27	Tho	Z-Di	3,3...27V, 5%, 0,25W		31a DO-7	Z-Diode V	31a	BZX55/..., BZX79/..., ZPD..., 1N5226...54,++
BZX 30/D3V3....27		Z-Di	=BZX 30/C...: 10%		31a DO-7	Z-Diode V	31a	›BZX 30/C...
BZX 31/C3V6....9V1	Tho	Z-Di	3,6...9,1V, 5%, 0,25W		31a DO-7	Z-Diode V	31a	BZX55/..., BZX79/..., ZPD..., 1N5227...39,++
BZX 32/C3V6....27	Tho	Z-Di	3,6...27V, 5%, 5W(Tc=25°)		32a (12x7mmØ)			BZX 98/..., 1N2970...88
BZX 32/D3V6....27		Z-Di	=BZX 32/C...: 10%		32a (12x7mmØ)			›BZX 32/C...
BZX 33	Tho	Ref-Di	8,6V(10mA), 0,2W, ±0,5mV/°C, <30Ω		31a (19x8mmØ)			1N3154...3157, 1N4775...4784
BZX 34	Tho	Ref-Di	8,6V(10mA), 0,2W, ±0,1mV/°C, <30Ω		31a (19x8mmØ)			1N3154...3157, 1N4775...4784
BZX 35	Tho	Ref-Di	10V(10mA), 0,2W, ±1,5mV/°C, <40Ω		31a (19x8mmØ)			-
BZX 36	Tho	Ref-Di	6,2V(5mA), 0,2W, -0,5...+1mV/°C, <60Ω		31a (19x8mmØ)			BZV 10...14, BZX 90...94, 1N4575...4584,++
BZX 43	Fch,Sgs	Ref-Di	6,7V, ±0,001%/°C, <750Ω		2d TO-18			BZV 13, BZX 48, BZX 93, 1N4578, 1N4890++
BZX 44	Fch,Sgs	Ref-Di	=BZX 43: ±0,002%/°C		2d TO-18			BZV 12, BZX 49, BZX 92, 1N4577, 1N4582++
BZX 45	Fch,Sgs	Ref-Di	=BZX 43: ±0,003%/°C		2d TO-18			BZV 12, BZX 49, BZX 92, 1N4577, 1N4582++
BZX 46/C2V7....200	Itt,Phi	Z-Di	2,7...200V, 5%, 0,5W		31a DO-35	Z-Diode V	31a	BZX55/..., BZX79/..., ZPD..., 1N5223...81,++
BZX 47	Phi	Ref-Di	6,5V(2mA), 10mA, ±0,0005%/°C, <50Ω		2c TO-18			BZV 14, BZX 94, 1N4574, 1N4579, 1N4584++
BZX 48	Phi	Ref-Di	=BZX 47: ±0,001%/°C		2c TO-18			BZV 13, BZX 43, BZX 93, 1N4578, 1N4583++
BZX 49	Phi	Ref-Di	=BZX 47: ±0,002%/°C		2c TO-18			BZV 12, BZX 44, BZX 92, 1N4577, 1N4582++
BZX 50	Phi	Ref-Di	=BZX 47: ±0,005%/°C		2c TO-18			BZV 11, BZX 45, BZX 91, 1N4576, 1N4581++
BZX 51	Aeg	Ref-Di	8,4V, 25mA, 0,25W, ±0,01%/°C, <9Ω		31a DO-7			1N3154, 1N4775, 1N4780
BZX 52	Aeg	Ref-Di	=BZX 51: ±0,005%/°C		31a DO-7			1N3155, 1N4776, 1N4781
BZX 53	Aeg	Ref-Di	=BZX 51: ±0,002%/°C		31a DO-7			1N3156, 1N4777, 1N4782
BZX 54	Aeg	Ref-Di	=BZX 51: ±0,001%/°C		31a DO-7			1N3157, 1N4778, 1N4783
BZX 55/A2V4....200	Aeg	Z-Di	=BZX 55/C...: 1%		31a DO-35	Z-Diode V	31a	›BZX 55/C...
BZX 55/B2V4....200	Aeg	Z-Di	=BZX 55/C...: 2%		31a DO-35	Z-Diode V	31a	›BZX 55/C...
BZX 55/C0V8	Itt,Sie,Tho	Si-St	0,73...0,83V(5mA), 0,5W		31a	(1N4148)	31a	BZ 102/0V7, BZX 83/C0V8, ZPD 1
BZX 55/C2V4....200	Phi,Sie,++	Z-Di	2,4...200V, 5%, 0,5W		31a DO-35	Z-Diode V	31a	BZW 22/..., BZX79/..., ZPD..., 1N5221...81++
BZX 55/D2V4....200	Sie	Z-Di	=BZX 55/D...: 10%		31a DO-35	Z-Diode V	31a	›BZX 55/C...
BZX 57	Tho	Z-Di	7,5V, 5%, 0,25W		31a DO-7	Z-Diode 7,5V	31a	BZX55/C7V5, BZX79/C7V5, ZPD7,5, 1N5236++
BZX 58/C6V8....10	Tho	Z-Di	6,8...10V, 5%, 0,25W		31a DO-7	Z-Diode V	31a	BZX55/..., BZX79/..., ZPD..., 1N5235...40,++
BZX 59/C11....27	Tho	Z-Di	11...27V, 5%, 0,25W		31a DO-7	Z-Diode V	31a	BZX55/..., BZX79/..., ZPD..., 1N5241...54,++
BZX 60/C30....56	Tho	Z-Di	30...56V, 5%, 0,25W		31a DO-7	Z-Diode V	31a	BZX55/..., BZX79/..., ZPD..., 1N5256...63,++
BZX 61/C3V6....200	Phi,Tho	Z-Di	3,6...200V, 5%, 1,3W		31a DO-15	Z-Diode V	31a	BZW22/..., BZX85/..., ZPY..., 1N5914...56,++
BZX 62	Phi,Tho	Si-St	0,65...0,75V(5mA), <1V(100mA), 0,25W		31a DO-7	(1N4148)	31a	BA 220, BZ 102/0V8, BZX 55/0V8, ZPD 1
BZX 63/C6V8....10	Tho	Z-Di	=BZX 58/...:		31a DO-41	Z-Diode V	31a	›BZX 58/...
BZX 64/C11....27	Tho	Z-Di	=BZX 59/...:		31a DO-41	Z-Diode V	31a	›BZX 59/...
BZX 65/C30....56	Tho	Z-Di	=BZX 60/...:		31a DO-41	Z-Diode V	31a	›BZX 60/...
BZX 66	Tho	Ref-Di	6,8V(5mA), 5%, 0,25W, -0,005...+0,08%/°C, <20Ω		2a TO-18			BZV 14, BZX 43...45, BZX 47...50, 1N4895++
BZX 67/C12....200	Aeg	Z-Di	12...200V, 5%, 10,7W(Tc=45°)		≈32a			BZX 98/..., 1N2976...3015
BZX 68 A	Aeg	Z-Di	58...61V, 10,7W(Tc=45°)		≈32a			(BZX 98/C62, 1N3000)
BZX 68 B		Z-Di	=BZX 68A: 61...63V		≈32a			BZX 98/C62, 1N3000
BZX 68 C		Z-Di	=BZX 68A: 63...66V		≈32a			(BZX 98/C62, 1N3000)
BZX 69/C7V5....12	Tho	Z-Di	7,5...12V, 5%, 0,25W		31a DO-7	Z-Diode V	31a	BZX55/..., BZX79/..., ZPD..., 1N5236...42,++
BZX 70/C7V5....75	Phi	Z-Di	Z, TAZ, 7,5...75V, 5%, 2,5W		31a SOD-18			BZD 23/..., BZT 03/..., BZW 70/...
BZX 71/B5V1....24	Aeg	Z-Di	5,1...24V, 2%, 0,4W		31a DO-35	Z-Diode V	31a	BZX55/..., BZX79/..., ZPD..., 1N5231...52,++
BZX 71/C5V1....24		Z-Di	=BZX 71/B...: 5%		31a DO-35	Z-Diode V	31a	›BZX 71/B...
BZX 72(A....C)	Fer	Ref-Di	9V(5mA), 5%, 0,0567W, ±0,001%/°C, <50Ω A: ±0,002%/°C, B: ±0,002%/°C, C: ±0,004%/°C		31a DO-7			1N938...936, 1N4768...66, 1N4773...71

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
BZX 74/C5V6....12	Ssc	Z-Di	5,6...12V, 5%, 0,4W		31a	DO-7	Z-Diode V	31a	BZX55/..., BZX79/..., ZPD..., 1N5232...42,++
BZX 75/C1V4....3V6	Fer,Phi	Si-St	1,4...3,6V(10mA), 5%, 0,4W		31a	DO-7	Z-Diode V	31a	BZ 102/..., BZV 86/...
BZX 76	Tho	Z-Di	13V, 5%, 0,4W		31a	DO-41	Z-Diode 13V	31a	BZX55/C13, BZX79/C13, ZPD13, 1N5243,++
BZX 77/D5V6....9V1	Tix	Z-Di	Min, 5,6...9,1V, 10%		Chip	≈TO-122			-
BZX 78/C5V1....75	Phi	Z-Di	SMD, 5,1...75V, 5%		39j	SOT-89			BZV 49/..., RD ...P
BZX 79/B2V4....200	Mot,Phi,Tho	Z-Di	2,4...200V, 2%, 0,4W		31a	DO-35	Z-Diode V	31a	BZX55/..., BZX85/..., ZPD..., 1N5221...81,++
BZX 79/C2V4....200		Z-Di	≈BZX 79/B...: 5%		31a	DO-35	Z-Diode V	31a	›BZX 79/B...
BZX 79/F2V4....200		Z-Di	≈BZX 79/B...: 3%		31a	DO-35	Z-Diode V	31a	›BZX 79/B...
BZX 80/C6V8....10	Tho	Z-Di	≈BZX 58/...: 0,8W		2d	TO-18L	Z-Diode V	31a	›BZX 58/...
BZX 81/C11....27	Tho	Z-Di	≈BZX 59/...: 0,8W		2d	TO-18L	Z-Diode V	31a	›BZX 59/...
BZX 82/C30....56	Tho	Z-Di	≈BZX 60/...: 0,8W		2d	TO-18L	Z-Diode V	31a	›BZX 60/...
BZX 83/C0V8	Aeg,Sie,++	Si-St	0,73...0,83V(5mA), 0,4A, 0,5W, <10Ω		31a	DO-35	(1N4148)	31a	BZW 22/C0V8, ZPY 1
BZX 83/C2V4....75	Aeg,Sie,++	Z-Di	2,4...75V, 5%, 0,5W		31a	DO-35	Z-Diode V	31a	BZX55/..., BZX79/..., ZPD..., 1N5221...67,++
BZX 84/A2V4....75		Z-Di	≈BZX 84/C...: 1%		35p	SOT-23			-
BZX 84/B2V4....75		Z-Di	≈BZX 84/C...: 2%		35p	SOT-23			-
BZX 84/C0V8	Sie	Si-St	SMD, 0,73...0,83V(5mA), -/0,2A, <8Ω		35p	SOT-23			-
BZX 84/C2V4....75	Phi,Sie,++	Z-Di	SMD, 2,4...75V, 5%		35p	SOT-23			HZM ..., RD ...M
BZX 85/C2V7....200	Aeg,Sie,++	Z-Di	2,7...200V, 5%, 1,3W		31a	DO-41	Z-Diode V	31a	BZW22/..., BZX61/..., ZPY..., 1N5913...56,++
BZX 86-E36	Phi	Z-Di	35...45V		73a	DO-30			-
BZX 87/C4V7....75	Phi	Z-Di	4,7...75V, 5%, 1,3W		31a	SOD-51	Z-Diode V	31a	BZW22/..., BZX61/..., ZPY..., 1N5917...46,++
BZX 88/C2V7....47	Fer	Z-Di	SMD, 2,7...47V, 5%		35p(2mm)	SOT-323			-
BZX 89/C7V5....12	Tho	Z-Di	7,5...12V, 5%, 0,4W		2	TO-18	Z-Diode V	31a	BZX55/..., BZX79/..., ZPD..., 1N5236...42,++
BZX 90	Phi	Ref-Di	6,5V(7,5mA), 5%, 50mA, 0,4W, ±0,01%/°C, <15Ω		31a	DO-35			BZV 10, 1N4565, 1N4570, 1N4575, 1N4580++
BZX 91	Phi	Ref-Di	≈BZX 90: ±0,005%/°C		31a	DO-35			BZV 11, 1N4566, 1N4571, 1N4576, 1N4581++
BZX 92	Phi	Ref-Di	≈BZX 90: ±0,002%/°C		31a	DO-35			BZV 12, 1N4567, 1N4572, 1N4577, 1N4582++
BZX 93	Phi	Ref-Di	≈BZX 90: ±0,001%/°C		31a	DO-35			BZV 13, 1N4568, 1N4573, 1N4578, 1N4583++
BZX 94	Phi	Ref-Di	≈BZX 90: ±0,0005%/°C		31a	DO-35			BZV 14, 1N4569, 1N4574, 1N4579, 1N4584++
BZX 95/C4V7....36	Hit	Z-Di	4,7...36V, 5%, 0,4W		31a	DO-35	Z-Diode V	31a	BZX55/..., BZX79/..., ZPD..., 1N5230...58,++
BZX 96/C2V4....33	Tho	Z-Di	2,4...33V, 5%, 0,4W		31a	DO-7	Z-Diode V	31a	BZX55/..., BZX79/..., ZPD..., 1N5221...57,++
BZX 97/C0V8	Itt,Sie	Si-St	0,73...0,83V(5mA), 0,5W, <8Ω		31a	DO-35	(1N4148)	31a	BA 315, BZX 62, BZ 102/0V7, BZX 55/C0V8
BZX 97/C2V4....62	Itt,Sie	Z-Di	2,4...62V, 5%, 0,5W		31a	DO-35	Z-Diode V	31a	BZX55/..., BZX79/..., ZPD..., 1N5221...65,++
BZX 98/C3V9....200	Sie	Z-Di	3,9...200V, 5%, 13W(Tc=85°)		32a	DO-4			BZY 93/...
BZY									
BZY 1	Eiy	Si-St	0,7...0,9V, 0,1A, 1,25W(Ta=25°)		32a				-
BZY 5	Eiy	Z-Di	5,5V, 10%, 1,25W(Ta=25°)		32a				BZX 98/...
BZY 6	Eiy	Z-Di	≈BZY 5: 6,5V		32a				›BZY 5
BZY 7	Eiy	Z-Di	≈BZY 5: 7,5V		32a				›BZY 5
BZY 8	Eiy	Z-Di	≈BZY 5: 8,5V		32a				›BZY 5
BZY 10	Eiy	Z-Di	≈BZY 5: 10V		32a				›BZY 5
BZY 12	Eiy	Z-Di	≈BZY 5: 12V		32a				›BZY 5
BZY 14	Aeg	Z-Di	5,6V, 10%, 3,5W(Tc=45°)		32a	(13x7mmØ)			BZY 98/...
BZY 15	Aeg	Z-Di	≈BZY 14: 6,8V		32a	(13x7mmØ)			›BZY 14
BZY 16	Aeg	Z-Di	≈BZY 14: 8,2V		32a	(13x7mmØ)			›BZY 14
BZY 16/C....	Ssc	Z-Di	≈BZV 16/C....						›BZV 16/C...
BZY 17	Aeg	Z-Di	≈BZY 14: 10V		32a				›BZY 14
BZY 17/C....	Ssc	Z-Di	≈BZV 17/C....						›BZV 17/C...
BZY 18	Aeg	Z-Di	≈BZY 14: 12V		32a				›BZY 14
BZY 18/C....	Ssc	Z-Di	≈BZV 18/C....						›BZV 18/C...
BZY 19	Aeg	Z-Di	≈BZY 14: 15V		32a				›BZY 14
BZY 20	Aeg	Z-Di	≈BZY 14: 18V		32a				›BZY 14
BZY 21	Aeg	Z-Di	≈BZY 14: 22V		32a				›BZY 14
BZY 22	Itt	Ref-Di	8,4V(5mA), 5%, 0,2W, ±0,01%/°C, <25Ω		33				-
BZY 23	Itt	Ref-Di	≈BZY 22: ±0,005%/°C		33				-
BZY 24	Itt	Ref-Di	≈BZY 22: ±0,002%/°C		33				-
BZY 25	Itt	Ref-Di	≈BZY 22: ±0,001%/°C		33				-
BZY 56	Phi	Z-Di	4,7V, 5%, 0,28W		31a	DO-7	Z-Diode 4,7V	31a	BZX55/..., BZX79/..., ZPD..., 1N5230...,++
BZY 57	Phi	Z-Di	≈BZY 56: 5,1V		31a	DO-7	Z-Diode 5,1V	31a	›BZY 56
BZY 58	Phi	Z-Di	≈BZY 56: 5,6V		31a	DO-7	Z-Diode 5,6V	31a	›BZY 56
BZY 59	Phi	Z-Di	≈BZY 56: 6,2V		31a	DO-7	Z-Diode 6,2V	31a	›BZY 56
BZY 60	Phi	Z-Di	≈BZY 56: 6,8V		31a	DO-7	Z-Diode 6,8V	31a	›BZY 56
BZY 61	Phi	Z-Di	≈BZY 56: 7,5V		31a	DO-7	Z-Diode 7,5V	31a	›BZY 56
BZY 62	Phi	Z-Di	≈BZY 56: 8,2V		31a	DO-7	Z-Diode 8,2V	31a	›BZY 56
BZY 63	Phi	Z-Di	≈BZY 56: 9,1V		31a	DO-7	Z-Diode 9,1V	31a	›BZY 56
BZY 64	Phi	Z-Di	≈BZY 56: 4,3V, 15%		31a	DO-7	Z-Diode 4,3V	31a	›BZY 56
BZY 65	Phi	Z-Di	≈BZY 56: 5,1V, 15%		31a	DO-7	Z-Diode 5,1V	31a	›BZY 56
BZY 66	Phi	Z-Di	≈BZY 56: 6,2V, 15%		31a	DO-7	Z-Diode 6,2V	31a	›BZY 56
BZY 67	Phi	Z-Di	≈BZY 56: 7,5V, 15%		31a	DO-7	Z-Diode 7,5V	31a	›BZY 56
BZY 68	Phi	Z-Di	≈BZY 56: 9,1V, 15%		31a	DO-7	Z-Diode 9,1V	31a	›BZY 56
BZY 69	Phi	Z-Di	≈BZY 56: 12V, 15%		31a	DO-7	Z-Diode 12V	31a	›BZY 56
BZY 70	Itt	Ref-Di	8,1V(100mA), 5%, 1W(Ta=100°C), 0,002%/°C,, <6Ω						-
BZY 71		Ref-Di	≈BZY 70: 2,5%, 0,001%/°C						-
BZY 74	Phi	Z-Di	6,2V, 15%		32a	DO-4			BZX 98/C6V2
BZY 75	Phi	Z-Di	≈BZY 74: 7,5V		32a	DO-4			BZX 98/C7V5
BZY 76	Phi	Z-Di	≈BZY 74: 9,2V		32a	DO-4			BZX 98/C9V2
BZY 78(P)	Phi	Z-Di	5,3V, 5%, 0,28W		31a	DO-7	Z-Diode 5,1V	31a	BZX55/C5V1, BZX79/C5V1, ZPD5,1, 1N5231++
BZY 83/C4V7....24V5	Aeg,Sie	Z-Di	4,7...24,5V, 5%, 0,25W		2c	TO-1	Z-Diode V	31a	BZX55/..., BZX79/..., ZPD..., 1N5230...53,++
BZY 83/D1	Aeg,Sie	Si-St	0,62...0,78V(5mA), 0,2A, 0,25W, <8Ω		2c	TO-1	(1N4148)	31a	BZ 102/0V8, BZX 55/C0V8, ZPD 1
BZY 83/D4V7....22	Aeg,Sie	Z-Di	≈BZY 83/C...: 10%		2c	TO-1	Z-Diode V	31a	›BZY 83/C...
BZY 84/D1	Sie	Si-St	0,7...0,9V(100mA), -/3A, 14W(Tc=45°)		≈32a				-
BZY 84/D5V6....12	Sie	Z-Di	5,6...12V, 10%, 14W(Tc=45°)		≈32a				BZX 98/...
BZY 85/B2V7....33	Aeg,Sie	Z-Di	2,7...33V, 2%, 0,4W		31a	DO-7	Z-Diode V	31a	BZX55/..., BZX79/..., ZPD..., 1N5223...57,++
BZY 85/C2V7....33		Z-Di	≈BZY 85/B...: 5%		31a	DO-7	Z-Diode V	31a	›BZY 85/B...
BZY 85/D1	Aeg,Sie	Si-St	0,62...0,78V(5mA), 0,2/0,3A, 0,4W, <7,6Ω		31a	DO-7	(1N4148)	31a	BZ 102/0V7, BZX 55/C0V8, ZPD 1
BZY 85/D4V7....22		Z-Di	≈BZY 85/B...: 10%		31a	DO-7	Z-Diode V	31a	›BZY 85/B...
BZY 87/0V7....3V4	Aeg	Si-St	0,7...3,4V(5mA), 0,25W		31a	DO-7	Z-Diode V	31a	BZ 102/...
BZY 88/C0V7	Mot,Phi	Si-St	0,71...0,8V(5mA), 0,25A, 0,4W, <15Ω		31a	DO-7	(1N4148)	31a	BZ 102/0V7, BZX 55/C0V8, ZPD 1
BZY 88/C2V7....36	Mot,Phi	Z-Di	2,7...36V, 5%, 0,4W		31a	DO-7	Z-Diode V	31a	BZX55/..., BZX79/..., ZPD..., 1N5223...58,++
BZY 91/C7V5....75	Phi	Z-Di	Z, TAZ, 7,5...75V, 5%, 75W(Tc=65°), (=BZW91/...)		32a	DO-5			BZW 91/...
BZY 91/C7V5R...75R		Z-Di	≈BZY 91/C...:		32b	DO-5			BZW 91/...R
BZY 92/C3V9....36	Aeg	Z-Di	3,9...36V, 5%, 1,1W		34a	DO-13	Z-Diode V	31a	BZW22/..., BZX61/..., ZY..., 1N5915...38
BZY 93/C6V8....75	Phi	Z-Di	Z, TAZ, 6,8...75V, 5%, 20W(Tc=75°), (=BZW 93/...)		32a	DO-4			BZW 93/...
BZY 93/C6V8R...75R		Z-Di	≈BZY 93/C...:		32b	DO-4			BZW 93/...R

Original	Fabric.	Constr.	Info	{Compl. Fig.		JAEGER	Fig.	International
BZY 94/C10....75	Phi	Z-Di	10...75V, 5%, 0,4W	31a	DO-7	Z-Diode V	31a	BZX55/..., BZX79/..., ZPD..., 1N5240...67,++
BZY 95/C10....75	Aeg,Phi	Z-Di	10...75V, 5%, 1,5W	34a	DO-1	Z-Diode V	31a	BZW22/..., BZX61/..., ZY..., 2N5925...46
BZY 96/C4V7....10	Phi	Z-Di	4,7...10V, 5%, 1,5W	34a	DO-1	Z-Diode V	31a	BZW22/..., BZX61/..., ZY..., 1N5917...25,++
BZY 97/C3V3....200	Sie,Tho	Z-Di	3,3...200V, 5%, 1,5W	31a	SOD-22	Z-Diode V	31a	BZW22/..., BZX61/..., ZY..., 1N5913...56,++
BZZ								
BZZ 10	Phi	Z-Di	6,15V, 10%, 0,28W	31a	DO-7	Z-Diode 6,2V	31a	BZX55/..., BZX79/..., ZPD..., 1N5233...,++
BZZ 11	Phi	Z-Di	=BZZ 10: 6,55V	31a	DO-7	Z-Diode 6,8V	31a	›BZZ 10
BZZ 12	Phi	Z-Di	=BZZ 10: 7,25V	31a	DO-7	Z-Diode 7,5V	31a	›BZZ 10
BZZ 13	Phi	Z-Di	=BZZ 10: 8,05V	31a	DO-7	Z-Diode 8,2V	31a	›BZZ 10
BZZ 14	Phi	Z-Di	5,6V, 5%, 10W(Tc=50°)	32a	DO-4			BZX 98/C5V6
BZZ 15	Phi	Z-Di	=BZZ 14: 6,2V	32a	DO-4			BZX 98/C6V2
BZZ 16	Phi	Z-Di	=BZZ 14: 6,8V	32a	DO-4			BZX 98/C6V8
BZZ 17	Phi	Z-Di	=BZZ 14: 7,5V	32a	DO-4			BZX 98/C7V5
BZZ 18	Phi	Z-Di	=BZZ 14: 8,2V	32a	DO-4			BZX 98/C8V2
BZZ 19	Phi	Z-Di	=BZZ 14: 9,1V	32a	DO-4			BZX 98/C9V1
BZZ 20	Phi	Z-Di	=BZZ 14: 10V	32a	DO-4			BZX 98/C10
BZZ 21	Phi	Z-Di	=BZZ 14: 11V	32a	DO-4			BZX 98/C11
BZZ 22	Phi	Z-Di	=BZZ 14: 12V	32a	DO-4			BZX 98/C12
BZZ 23	Phi	Z-Di	=BZZ 14: 13V	32a	DO-4			BZX 98/C13
BZZ 24	Phi	Z-Di	=BZZ 14: 15V	32a	DO-4			BZX 98/C15
BZZ 25	Phi	Z-Di	=BZZ 14: 16V	32a	DO-4			BZX 98/C16
BZZ 26	Phi	Z-Di	=BZZ 14: 18V	32a	DO-4			BZX 98/C18
BZZ 27	Phi	Z-Di	=BZZ 14: 20V	32a	DO-4			BZX 98/C20
BZZ 28	Phi	Z-Di	=BZZ 14: 22V	32a	DO-4			BZX 98/C22
BZZ 29	Phi	Z-Di	=BZZ 14: 24V	32a	DO-4			BZX 98/C24
C								
C....	JAP	...-N	›2SC...., z.B./e.g. "C1398"=2SC1398 ›	Japantypen				
C....	Sam	...-N	›KSC...., z.B./e.g. "C1009"=KSC1009 ›	Samsung				
C....	Nec	IC	›µPC.... (NEC !)					
C		N-FET	=2SK1375 (SMD-Marking)	35(2mm)	SOT-323			›2SK1375
C		GaAs-N-FET	=2SK649 (Marking)	51				›2SK649
C		C-Di	=HVR 17 (SMD-Marking)	71(2,7mm)	SOD-123			›HVR 17
C		Si-Di	=MA 2S784 (SMD-Marking)	71(1,7mm)	SOD-323			›MA 784
C 1		Si-Di	=HSM 88(A)S (SMD-Marking)	35	SOT-23			›HSM 88(A)S
C 1		Si-Di	=HSM 88(A)SR(SMD-Marking)	35	SOT-23			›HSM 88(A)SR
C 1		Si-Di	=1SS352 (SMD-Marking)	71(1,7mm)	SOD-323			›1SS352
C 1		Si-Di	=1SS368 (SMD-Marking)	71(1,3mm)				›1SS368
C 1(p)		Si-P	=BCW 29 (SMD-Marking)	35	SOT-23			›BCW 29
C 1		Si-N	=BFS 38A (SMD-Marking)	35(2mm)	SOT-323			›BFS 38A
C 1 G		Si-N	=KSC 1632-G (SMD-Marking)	35	SOT-23			›KSC 1632
C 1 G		Si-N	=HN 1C01F-GR (SMD-Marking)	46	SOT-163			›HN 1C01F
C 1 G		Si-N	=HN 1C01FU-GR (SMD-Marking)	46(2mm)	SOT-363			›HN 1C01FU
C 1 L		Si-N	=KSC 1632-L (SMD-Marking)	35	SOT-23			›KSC 1632
C 1 O		Si-N	=KSC 1632-O (SMD-Marking)	35	SOT-23			›KSC 1632
C 1 Y		Si-N	=KSC 1632-Y (SMD-Marking)	35	SOT-23			›KSC 1632
C 1 Y		Si-N	=HN 1C01F-Y (SMD-Marking)	46	SOT-163			›HN 1C01F
C 1 Y		Si-N	=HN 1C01FU-Y (SMD-Marking)	46(2mm)	SOT-363			›HN 1C01FU
C 2		Si-P	=BFQ 32C (Marking)	51				›BFQ 32C
C 2(p)		Si-P	=BCW 30 (SMD-Marking)	35	SOT-23			›BCW 30
C 2		Si-P	=BFQ 32C (Marking)	51				›BFQ 32C
C 2		Si-N	=BFS 38 (SMD-Marking)	35(2mm)	SOT-323			›BFS 38
C 2		Si-Di	=HSM 276S (SMD-Marking)	35	SOT-23			›HSM 276S
C 3		Si-N	=BFS 39 (SMD-Marking)	35(2mm)	SOT-323			›BFS 39
C 3		Si-P	=MMBT 4126 (SMD-Marking)	35	SOT-23			›MMBT 4126
C 3		Si-Di	=1SS226 (SMD-Marking)	35	SOT-23			›1SS226
C 3		Si-Di	=1SS302 (SMD-Marking)	35(2mm)	SOT-323			›1SS302
C 3		Si-Di	=1SS362 (SMD-Marking)	35(1,6mm)	SS Mini			›1SS362
C 3 A		Si-N	=HN 1C03F-A (SMD-Marking)	46	SOT-163			›HN 1C03F
C 3 B		Si-N	=HN 1C03F-B (SMD-Marking)	46	SOT-163			›HN 1C03F
C 3 T		Si-Di	=1PS226 (SMD-Marking)	35	SOT-23			›1PS226
C 4		Si-P	=2SA811 (SMD-Marking)	35	SOT-23			›2SA811
C 4		Si-P	=BCW 29R (SMD-Marking)	35	SOT-23			›BCW 29R
C 4		Si-P	=BFS 40A (SMD-Marking)	35(2mm)	SOT-323			›BFS 40A
C 4		Si-Di	=HSM 88WK (SMD-Marking)	35	SOT-23			›HSM 88WK
C 4		Si-Di	=MC 804 (SMD-Marking)	35	SOT-23			›MC 804
C 5		Si-P	=2SA811-C5 (SMD-Marking)	35	SOT-23			›2SA811
C 5		Si-P	=BCW 30R (SMD-Marking)	35	SOT-23			›BCW 30R
C 5		Si-P	=BFS 40 (SMD-Marking)	35(2mm)	SOT-323			›BFS 40
C 5		GaAs-N-FET-d	=CFY 25-17 (Marking)	51				›CFY 25
C 5		Si-Di	=HSM 107S (SMD-Marking)	35	SOT-23			›HSM 107S
C 5		Si-P	=MMBA 811C5 (SMD-Marking)	35	SOT-23			›MMBA 811
CF 5R		GaAs-FET	=CF 930R (SMD-Marking)	44	SOT-143			›CF 930R
C 6		Si-P	=2SA811-C6 (SMD-Marking)	35	SOT-23			›2SA811
C 6		Si-P	=BFS 41 (SMD-Marking)	35(2mm)	SOT-323			›BFS 41
C 6		GaAs-N-FET-d	=CFY 25-20 (Marking)	51				›CFY 25
C 6		Si-Di	=HSM 198S (SMD-Marking)	35	SOT-23			›HSM 198S
C 6		Si-P	=MMBA 811C6 (SMD-Marking)	35	SOT-23			›MMBA 811
C 7		Si-P	=2SA811-C7 (SMD-Marking)	35	SOT-23			›2SA811
C 7(p)		Si-P	=BCF 29 (SMD-Marking)	35	SOT-23			›BCF 29
C 7		GaAs-N-FET-d	=CFY 25-23 (Marking)	51				›CFY 25
C 7		Si-Di	=HSM 88WA (SMD-Marking)	35	SOT-23			›HSM 88WA
C 7		Si-P	=MMBA 811C7 (SMD-Marking)	35	SOT-23			›MMBA 811
C 8		Si-P	=2SA811-C8 (SMD-Marking)	35	SOT-23			›2SA811
C 8(p)		Si-P	=BCF 30 (SMD-Marking)	35	SOT-23			›BCF 30
C 8		Si-P	=MMBA 811C8 (SMD-Marking)	35	SOT-23			›MMBA 811
C 9		Si-P	=BCF 30R (SMD-Marking)	35	SOT-23			›BCF 30R
C 10	old	C-Di	=BA 101	31a				›BA 101
C 15	old	C-Di	=BA 102	31a				›BA 102
C 15		Si-P	=2SA1612-C15 (SMD-Marking)	35(2mm)	SOT-323			›2SA1612
C 15		Si-P	=2SA811A-C15(SMD-Marking)	35	SOT-23			›2SA811A
C 16		Si-P	=2SA1612-C16 (SMD-Marking)	35(2mm)	SOT-323			›2SA1612